Hitachi 16-Bit Single-chip Microcomputer

H8S/2357 Series,

H8S/2357

H8S/2352

H8S/2390

H8S/2392

H8S/2394

H8S/2398

H8S/2357F-ZTATTM H8S/2398F-ZTATTM H8S/2396F-ZTATTM H8S/2395F-ZTATTM

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Hardware Manual





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Preface

This LSI is a single-chip microcomputer with a 32-bit H8S/2000 CPU core, and a set of on-chip peripheral functions required for system configuration.

This LSI is equipped with ROM, RAM, a bus controller, a data transfer controller (DTC), a programmable pulse generator (PPG), three types of timers, a serial communication interface (SCI), a D/A converter, an A/D converter, and I/O ports as on-chip peripheral functions. This LSI is suitable for use as an embedded microcomputer for high-level control systems. Its on-chip ROM is flash memory (F-ZTAT^{TM*}), PROM (ZTAT^{®*}), or mask ROM that provides flexibility as it can be reprogrammed in no time to cope with all situations from the early stages of mass production to full-scale mass production. This is particularly applicable to application devices with specifications that will most probably change.

Note: * F-ZTATTM is a trademark of Hitachi, Ltd.

ZTAT[®] is a registered trademark of Hitachi, Ltd.

Target Users: This manual was written for users who will be using the H8S/2357 Series in the

design of application systems. Members of this audience are expected to understand the fundamentals of electrical circuits, logical circuits, and

microcomputers.

Objective: This manual was written to explain the hardware functions and electrical

characteristics of the H8S/2357 Series to the above audience.

Refer to the H8S/2600 Series, H8S/2000 Series Programming Manual for a

detailed description of the instruction set.

Notes on reading this manual:

In order to understand the overall functions of the chip
 Read the manual according to the contents. This manual can be roughly categorized into parts on the CPU, system control functions, peripheral functions, and electrical characteristics.

In order to understand the details of the CPU's functions
 Read the H8S/2600 Series, H8S/2000 Series Programming Manual.

• In order to understand the details of a register when its name is known

The addresses, bits, and initial values of the registers are summarized in Appendix B, Internal I/O Register.

Examples: Bit order: The MSB is on the left and the LSB is on the right.

Related Manuals: The latest versions of all related manuals are available from our web site.

Please ensure you have the latest versions of all documents you require.

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http://www.hitachisemiconductor.com/

H8S/2357 Series users manuals:

Manual Title	ADE No.
H8S/2357 Series Hardware Manual	This manual
H8S/2600 Series, H8S/2000 Series Programming Manual	ADE-602-083

Users manuals for development tools:

Manual Title	ADE No.
C/C++ Compiler, Assembler, Optimized Linkage Editor Users Manual	ADE-702-247
Simulator Debugger Users Manual	ADE-702-037
Hitachi Embedded Workshop Users Manual	ADE-702-201

Application Note:

Manual Title	ADE No.
H8S Series Technical Q & A	ADE-502-059

Main Revisions and Additions in this Edition

Section	Item	Revisions (See Manual for Details)
All pages of this manual	Preface	Amendments due to introduction of the H8S/2395 F-ZTAT, H8S/2396 F-ZTAT, H8S/2398 F-ZTAT, and H8S/2398
1.1 Overview	Table 1-1 Overview	Contents of memory table added and notes amended
		Operating modes description added and notes added/amended
		Product lineup description added and notes added/amended
1.2 Block Diagram	Figure 1-1 Block Diagram	Notes amended
1.3 Pin Description	1.3.1 Pin Arrangement	Description added
1.3.2 Pin Functions in Each Operating Mode	Table 1-2 Pin Functions in Each Operating Mode	Pin name description amended
		Notes amended/added
3.1.2 Operating Mode Selection	Table 3-2 MCU Operating Mode Selection	Notes amended/added
3.3	3.3.2 Mode 2	Description added
Operating Mode Descriptions	3.3.3 Mode 3	
3.4 Pin Functions in Each Operating Mode	Table 3-4 Pin Functions in Each Operating Mode	Modes 2 and 3 added and notes amended

Section	Item	Revisions (See Manual for Details)
3.5 Memory Map in Each Operating Mode	Figure 3-1 Memory Map in Each Operating Mode (H8S/2357, H8S/2352) (1)	Notes amended
	Figure 3-5 Memory Map in Each Operating Mode (H8S/2396) (1)	Figure added
	Figure 3-6 Memory Map in Each Operating Mode (H8S/2395) (1)	Figure added
	Figure 3-7 Memory Map in Each Operating Mode (H8S/2398) (1)	Figure added
4.1.3 Exception Vector Table	4.1.3 Exception Vector Table	Description amended/added and note added
5.1.2 Block Diagram	Figure 5-1 Block Diagram of Interrupt Controller	Internal interrupt source modified
5.2 Register Descriptions	5.2.1 System Control Register (SYSCR)	Description added
5.6.3 Operation	(1) Selection of Interrupt Source	Description modified
	(3) Operation Order	Description modified
6.2 Register Descriptions	6.2.1 Bus Width Control Register (ABWCR)	Notes modified
6.2.5 Bus Control Register L (BCRL)	Bit 5–External Address Enable (EAE)	Notes added
6.3.4 Advanced Mode	Area 0	Description modified
6.8.2 Pin States in Idle Cycle	Table 6-8 Pin States in Idle Cycle	Notes added
6.9 Write Data Buffer Function	Figure 6-36 Example of Timing when Write Data Buffer Function is Used	Notes added

Section	Item	Revisions (See Manual for Details)
6.10.3 Pin States in External Bus Released State	Table 6-9 Pin States in Bus Released state	Notes added
7.1.1 Features	Activation sources: internal interrupt, external request, auto-request (depending on transfer mode)	Description amended from "transmission complete" to "transmission data empty"
7.1.3 Overview of Functions	Table 7-1 (1) Overview of DMAC Functions (Short Address Mode)	Description in Transfer Source amended from "transmission complete" to "transmission data empty"
	Table 7-1 (2) Overview of DMAC Functions (Full Address Mode)	In block transfer mode, description in Transfer Source amended from "transmission complete" to "transmission data empty"
7.2.4 DMA Control Register (DMACR)	Channel A	Description amended from "transmission complete" to "transmission data empty"
	Channel B	Description amended from "transmission complete" to "transmission data empty"
7.3.4 DMA Control Register (DMACR)	Block Transfer Mode	Description amended from "transmission complete" to "transmission data empty"
7.5.1 Transfer Modes	Table 7-5 DMAC Transfer Modes	Description amended from "transmission complete" to "transmission data empty"
9.1 Overview	Table 9-1 Port Functions	Notes amended/added
9.5.1 Overview	Figure 9-4 Port 4 Pin Functions	Figure modified
9.8.2 Register Configuration	Table 9-13 Port A Registers	Notes amended
9.12.2 Register Configuration	Table 9-21 Port E Registers	Notes amended

Section	Item	Revisions (See Manual for Details)
10.4.5 Cascaded Operation	Figure 10-23 Example of Cascaded Operation (2)	Description amended from "TCLKA" to "TCLKC" and from "TCLKB" to "TCLKD"
13.2.3 Reset Control/Status Register (RSTCSR)	Bit 5-Reset Select (RSTS)	Note amended
14.2.7 Serial Status Register (SSR)	14.2.7 Serial Status Register (SSR)	Description amended
18.3 Operation	18.3 Operation	Note added
19.1 Overview	19.1 Overview	Description amended
19.2.2 Bus Control Register L (BCRL)	Bit 5–External Address Enable (EAE)	Notes added
19.3 Operation	Table 19-3 Operating Modes and ROM Area	Notes added
19.13.3 Programmer Mode Operation	Table 19-19 Setting for Each Operating Mode in Programmer Mode	Pin names modified
19.13.5 Auto- Program Mode	Figure 19-29 Auto-Program Mode Timing Waveforms	Pin names modified
	Notes on Use of Auto- Program Mode	Modified
19.13.6 Auto- Erase Mode	Figure 19-30 Auto-Erase Mode Timing Waveforms	Pin names modified
	Notes on Use of Auto- Erase Mode	Modified
19.13.7 Status Read Mode	Figure 19-31 Status Read Mode Timing Waveforms	Pin names modified
	Table 19-27 Status Read Mode Return Commands	Pin names and note modified

Section	Item	Revisions (See Manual for Details)
19.15 Overview of	All pages from 19.15 Overview of Flash Memory to 19.32 Flash Memory Programming and Erasing Precautions	Added
19.17.1 Boot Mode	Table 19-36 System Clock Frequencies for which Automatic Adjustment of H8S/2339 or H8S/2329F- ZATA Bit Rate is Possible	Description amended
	On-Chip RAM Area Divisions in Boot Mode	Description amended
	Figure 19-46 RAM Areas in Boot Mode	Description amended
	Notes on Use of Boot Mode	Description amended
19.19 Hardware Protection	Table 19-37 Hardware Protection	Description added
19.23 Flash Memory Programming and Erasing Precautions	Use the specified voltages and timing for programming and erasing	Description amended
19.24.7 Block Configuration	19.24.7 Block Configuration	Description amended
19.25.2 Flash Memory Control Register 2 (FLMCR2)	19.25.2 Flash Memory Control Register 2 (FLMCR2)	Description amended
	Bit 6-Software Write Enable Bit 2 (SWE2)	Description added
	Bit 5–Erase Setup Bit 2 (ESU2)	Description added
	Bit 4–Program Setup Bit 2 (PSU2)	Description added

Section	Item	Revisions (See Manual for Details)
19.25.2 Flash Memory Control Register 2 (FLMCR2)	Bit 3–Erase-Verify 2 (EV2)	Description added
	Bit 2-Program-Verify 2 (PV2)	Description added
	Bit 1-Erase 2 (E2)	Description added
	Bit 0-Program 2 (P2)	Description added
19.26.1 Boot	Table 19-57 System Clock	Description amended
Mode	Frequencies for which Automatic Adjustment of H8S/2319F-ZTAT Bit Rate is Possible	Frequencies amended
	Notes on Use of Boot Mode	Description amended
19.26.2 User Program Mode	19.26.2 User Program Mode	Description added
19.27 Programming/E rasing Flash Memory	19.27 EProgramming/Erasing Flash Memory	Notes added
	19.27.1 Program Mode	Description amended and notes added
	19.27.2 Program-Verify Mode	Note added
19.27.3 Erase Mode	19.27.3 Erase Mode	Note added
19.27.4 Erase- Verify Mode	-19.27.4 Erase-Verify Mode	Note added
19.28.2 Software Protection	Table 19-59 Software Protection	Description and note added
19.32 Flash Memory Programming and Erasing Precautions	Use the specified voltages and timing for programming and erasing	Description amended
	Use the recommended algorithm when programming and erasing flash memory	Description added

Section	Item	Revisions (See Manual for Details)
19.32 Flash Memory Programming and Erasing Precautions	Notes on setting and clearing the SWE1 and SWE2 bits	Description replaced
20.2 Register Descriptions	20.2.1 System Clock Control Register (SCKCR)	Description and note added
	Bit 5–Reserved	Description amended
	Bits 4 and 3–Reserved	Added
20.3.1 Connecting a Crystal Resonator	Table 20-2 Damping Resistance Value	Frequency (10 MHz) added
21.2.2 System Clock Control Register (SCKCR)	21.2.2 System Clock Control Register (SCKCR)	Note added
	Bit 5–Reserved	Description amended
	Bits 4 and 3-Reserved	Added
22.1 Electrical Characteristics of Mask ROM Version (H8S/2398) and ROMless Versions (H8S/2394, H8S/2392, and H8S/2390)	22.1.1 Absolute Maximum Ratings	Note amended
22.1.2 DC Characteristics	Table 22-2 DC Characteristics	Port 1, A to C: added as output low voltage
		Note 2 amended
22.1.3 AC Characteristics	Table 22-5 Control Signal Timing	$t_{\text{NMTRS}}, t_{\text{NMIRH}}$ deleted
	Figure 22-14 Burst ROM Access Timing (Two-State Access)	Amended
	Figure 22-15 Burst ROM Access Timing (One-State Access)	Amended

Section	Item	Revisions (See Manual for Details)
22.2 Usage Note	22.2 Usage Note	Description amended
	Figure 22-32 V _{CL} Capacitor Connection Method	Description amended
22.3 Electrical	All pages from 22.3 Electrical Characteristics of F-ZTAT Versions (H8S/2398, H8S/2396, and H8S/2395) (Preliminary) to 22.5 Usage Note	Added
22.3.6 Flash Memory Characteristics	Characteristics	Z for wait time after P bit setting, in programming, amended, and notes added
22.6.3 AC Characteristics	Figure 22-78 Burst ROM Access Timing (Two-State Access)	Amended
	Figure 22-79 Burst ROM Access Timing (One-State Access)	Amended
A.2 Instruction Codes	A.2 Instruction Codes	MOV mnemonic description amended
B. Internal I/O Register	B.1 Addresses	Address H'FEDB added
		Notes 7, 8, 9, and 10 added to SYSCR2 of address H'FF42
		Address H'FFAC added
		FLASH addresses added
	Notes added	
	H'FED5: Bus Control Register L BCRL: Bus Controller	Notes added
	H'FEDB: RAM Emulation Register RAMER: Bus Controller	Added

Section	Item	Revisions (See Manual for Details)
B. Internal I/O Register	H'FF02: DMA Control Register 0A DMACR0A: DMAC	Description of block transfer mode of data transfer factor amended from "transmission complete" to "transmission data empty"
	H'FF03: DMA Control Register 0B DMACR0B: DMAC	Description of data transfer factor amended from "transmission complete" to "transmission data empty"
	H'FF04: DMA Control Register 1A DMACR1A: DMAC	
	H'FF05: DMA Control Register 1B DMACR1B: DMAC	
	H'FF39: System Control Register SYSCR: MCU	Description added
	H'FF3A: System Clock Control Register SCKCR: Clock Pulse Generator	Description added
	H'FF7A: Serial Control Register 0 SCR0: SCI0	Description of 1 of Multiprocessor Interrupt Enable Bit added
	H'FF82: Serial Control Register 1 SCR1: SCI1	Description of 1 of Multiprocessor Interrupt Enable Bit added
	H'FF8A: Serial Control Register 2 SCR2: SCI2	Description of 1 of Multiprocessor Interrupt Enable Bit added
	H'FFAC: Reserved Register DACR: D/A	Added
	H'FFC8: Flash Memory Control Register 1 FLMCR1: FLASH to H'FFCB: Erase Block Specification Register 2 EBR2: FLASH	Added
D.1 Port Status in Each Mode	Table D-1 I/O Port States in Each Processing State	Port name pin name amended from "IR15" to "IRQS"
H. Packages	Table H-2 Packages of H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390	Added Note 2 added

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Section 1 Overview

1.1 Overview

The H8S/2357 Series is a series of microcomputers (MCUs: microcomputer units), built around the H8S/2000 CPU, employing Hitachi's proprietary architecture, and equipped with peripheral functions on-chip.

The H8S/2000 CPU has an internal 32-bit architecture, is provided with sixteen 16-bit general registers and a concise, optimized instruction set designed for high-speed operation, and can address a 16-Mbyte linear address space. The instruction set is upward-compatible with H8/300 and H8/300H CPU instructions at the object-code level, facilitating migration from the H8/300, H8/300L, or H8/300H Series.

On-chip peripheral functions required for system configuration include DMA controller (DMAC) and data transfer controller (DTC) bus masters, ROM and RAM memory, a 16-bit timer-pulse unit (TPU), programmable pulse generator (PPG), 8-bit timer, watchdog timer (WDT), serial communication interface (SCI), A/D converter, D/A converter, and I/O ports.

Single-power-supply flash memory (F-ZTAT*1), PROM (ZTAT*2), and mask ROM versions are available, providing a quick and flexible response to conditions from ramp-up through full-scale volume production, even for applications with frequently changing specifications.

The features of the H8S/2357 Series are shown in Table 1-1.

Notes: 1. F-ZTAT is a trademark of Hitachi, Ltd.

2. ZTAT is a trademark of Hitachi, Ltd.

Table 1-1 Overview

Item	Specification		
CPU	General-register machine		
	 Sixteen 16-bit general registers (also usable as sixteen 8-bit registers or eight 32-bit registers) 		
	 High-speed operation suitable for realtime control 		
	Maximum clock rate: 20 MHz		
	 High-speed arithmetic operations 		
	8/16/32-bit register-register add/subtract: 50 ns		
	16×16 -bit register-register multiply: 1000 ns		
	32 ÷ 16-bit register-register divide: 1000 ns		
	 Instruction set suitable for high-speed operation 		
	 Sixty-five basic instructions 		
	 8/16/32-bit move/arithmetic and logic instructions 		
	 Unsigned/signed multiply and divide instructions 		
	 Powerful bit-manipulation instructions 		
	CPU operating modes		
	 Advanced mode: 16-Mbyte address space 		
Bus controller	 Address space divided into 8 areas, with bus specifications settable independently for each area 		
	Chip select output possible for each area		
	Choice of 8-bit or 16-bit access space for each area		
	 2-state or 3-state access space can be designated for each area 		
	 Number of program wait states can be set for each area 		
	Burst ROM directly connectable		
	 Maximum 8-Mbyte DRAM directly connectable (or use of interval timer possible) 		
	External bus release function		
DMA controller	Choice of short address mode or full address mode		
(DMAC)	 4 channels in short address mode 		
	 2 channels in full address mode 		
	 Transfer possible in repeat mode, block transfer mode, etc. 		
	 Single address mode transfer possible 		
	Can be activated by internal interrupt		
Data transfer	Can be activated by internal interrupt or software		
controller (DTC)	 Multiple transfers or multiple types of transfer possible for one activation source 		
	 Transfer possible in repeat mode, block transfer mode, etc. 		
	 Request can be sent to CPU for interrupt that activated DTC 		

Item	em Specification				
16-bit timer-pulse unit (TPU)	 6-channel 16-bit timer on-chip Pulse I/O processing capability for up to 16 pins' Automatic 2-phase encoder count capability 				
Programmable pulse generator (PPG)	Maximum 16-bit pulse output possible with TPU as time base				
8-bit timer 2 channels	 Brief output of inverse output setting possible 8-bit up-counter (external event count capability) Two time constant registers Two-channel connection possible 				
Serial communication interface (SCI) 3 channels	 Watchdog timer Watchdog timer or interval timer selectable Asynchronous mode or synchronous mode selectable Multiprocessor communication function Smart card interface function 				
A/D converter	 Resolution: 10 bits Input: 8 channels High-speed conversion: 6.7 µs minimum conversion time (at 20 MHz operation) Single or scan mode selectable Sample and hold circuit A/D conversion can be activated by external trigger or timer trigger 				
D/A converter	Resolution: 8 bitsOutput: 2 channels	·	<u> </u>		
I/O ports Memory	 87 I/O pins, 8 input-c Flash memory, PRO High-speed static RA Product Name 	M, Mask ROM	RAM		
	H8S/2357	128 kbytes	8 kbytes		
	H8S/2352	_	8 kbytes		
	H8S/2398*1	256 kbytes	8 kbytes		
	H8S/2396* ²	512 kbytes	8 kbytes		
	H8S/2395* ²	384 kbytes	8 kbytes		
	H8S/2394*1	_	32 kbytes		
	H8S/2392	_	8 kbytes		
	H8S/2390 — 4 kbytes		4 kbytes		
	Notes: 1. Under develop 2. In Planning.	oment.			

Item	Specification		
Interrupt controller	Nine external interrupt pins (NMI, IRQ0 to IRQ7)		
	52 internal interrupt sources		
	Eight priority levels settable		
Power-down state	Medium-speed mode		
	Sleep mode		
	Module stop mode		
	Software standby mode		
	Hardware standby mode		
Operating modes	Fight MCLL operating modes (H8S/2357F-7TAT version)		

Operating modes

• Eight MCU operating modes (H8S/2357F-Z1A1 version)

	CPU			Extern	al Data Bus
Mode	Operating Mode	Description	On-Chip ROM	Initial Value	Maximum Value
0	_	_	_	_	_
1	=				
2	_				
3	_				
4	Advanced	nced On-chip ROM disabled	Disabled	16 bits	16 bits
5	_	expansion mode		8 bits	16 bits
6	_	On-chip ROM enabled expansion mode	Enabled	8 bits	16 bits
7	=	Single-chip mode	_	_	_
8	_	_	_	_	_
9	_				
10	Advanced	Boot mode	Enabled	8 bits	16 bits
11	_			_	_
12	_	_	_	_	_
13					
14	Advanced	User program mode	Enabled	8 bits	16 bits
15				_	_

Item	Specifi	cation					
Operating			ing modes (H8S/2395, H8S/ lless, and ZTAT versions)	2396, and H	8S/2398 F	-ZTAT,	
modes		CPU			External Data Bus		
	Mode	Operating Mode	Description	On-Chip ROM	Initial Value	Maximum Value	
	0	_	_	_	_	_	
	1	_					
	2*1	_					
	3*1	_					
	4*2	Advanced	On-chip ROM disabled expansion mode	Disabled	16 bits	16 bits	
	5*2	_	On-chip ROM disabled expansion mode	Disabled	8 bits	16 bits	
	6	_	On-chip ROM enabled expansion mode	Enabled	8 bits	16 bits	
	7	_	Single-chip mode	Enabled	_	_	
	Notes:	versions, of the H8 19-56 in s boot mod section 19 In additio to tables Programr	S/2395 F-ZTAT, H8S/2396 F modes 2 and 3 indicate boo S/2395 F-ZTAT and H8S/23 section 19.26, On-Board Proe of the H8S/2398 F-ZTAT v9.17, On-Board Programmin n, for details on user prograr 19-56 and 19-35 in sections ming Modes.	t mode. For of 96 F-ZTAT v gramming M version, refer g Modes. n mode of sa 19.26 and 19	details on ersions, re odes. For to table 1 id produc 0.17, On-E	boot mode efer to table details on 9-35 in ts, refer also	
		Z. III KOMIE	ss version, only modes 4 an	u 5 ale avall	abie.		

Clock pulse • generator

Built-in duty correction circuit

Item	Specification								
Packages		120-pin plastic TQFP (TFP-120) 128 pin plastic QFP (FP-128)							
Product		5 V version		3.3 V version	3 V version				
lineup	Operating Supply Voltage	5 V ± 10%		3.0 to 5.5 V	2.7 to 5.5 V				
	Operating Frequency	2 to 20 MHz	10 to 20 MHz	2 to 13 MHz	2 to 10 MHz				
	ROMless Version	HD6412352F20 HD6412352TE20	HD6412394F20* ³ HD6412394TE20* ³ HD6412392F20 HD6412392TE20 HD6412390F20 HD6412390TE20	HD6412352F13 HD6412352TE13	HD6412352F10 HD6412352TE10				
	Mask ROM Version	HD6432357(A**)F HD6432357(A**)TE	HD6432398(A**)F* ³ HD6432398(A**)TE* ³	HD6432357(M**)F HD6432357(M**)TE	HD6432357(K**)F HD6432357(K**)TE				
	F-ZTAT Version* ²	HD64F2357F20 HD64F2357TE20	HD64F2398F20*3 HD64F2398TE20*3 HD64F2396F20*4 HD64F2396TE20*4 HD64F2395F20*4 HD64F2395TE20*4	HD64F2357VF13 HD64F2357VTE13	_				
	ZTAT Version	HD6472357F20 HD6472357TE20	_	HD6472357F13 HD6472357TE13	HD6472357F10 HD6472357TE10				
	Packages	FP-128 TFP-120		FP-128 TFP-120	FP-128 TFP-120				
	Notes: 1. In mask ROM versions, (**) is the ROM code. 2. See sections 22.3.6 and 22.7.6, Flash Memory Characteristics, for flash version operating supply voltage and temperature range for programming/erasing. 3. Under development 4. In Planning								

1.2 Block Diagram

Figure 1-1 shows an internal block diagram of the H8S/2357 Series.

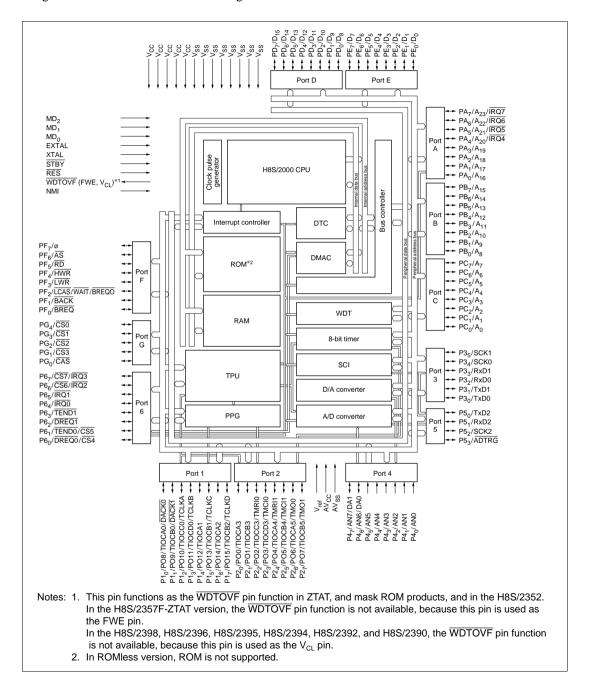


Figure 1-1 Block Diagram

1.3 Pin Description

1.3.1 Pin Arrangement

Figures 1-2 and 1-3 show the pin arrangement for the H8S/2357, H8S/2352 and figures 1-4 and 1-5 show the pin arrangements for the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390.

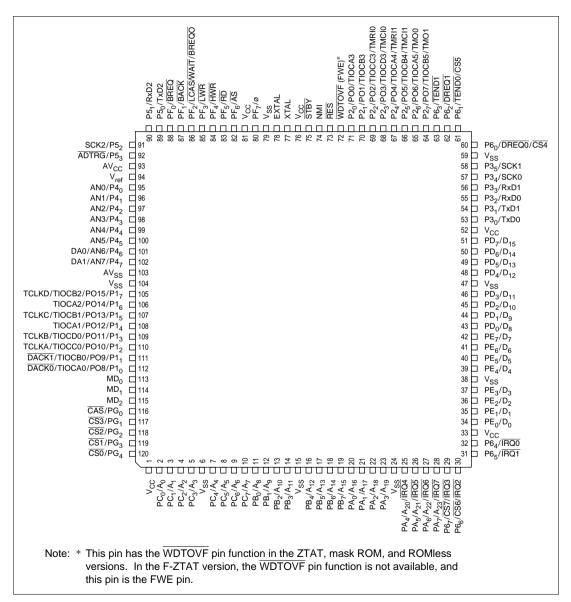


Figure 1-2 H8S/2357, H8S/2352 Pin Arrangement (TFP-120: Top View)

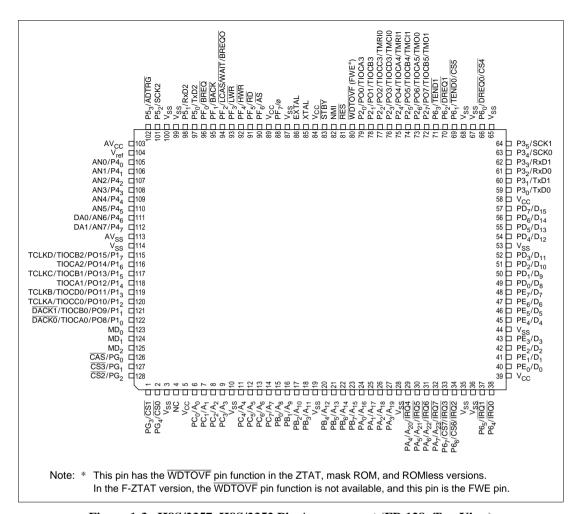


Figure 1-3 H8S/2357, H8S/2352 Pin Arrangement (FP-128: Top View)

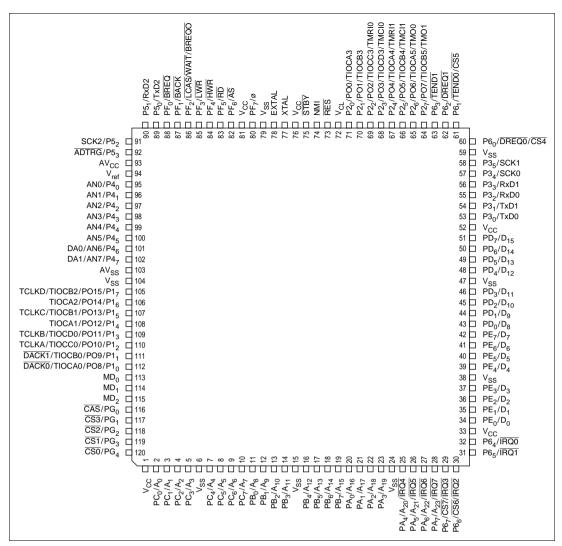


Figure 1-4 H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, H8S/2390 Pin Arrangement (FP-120: Top View)

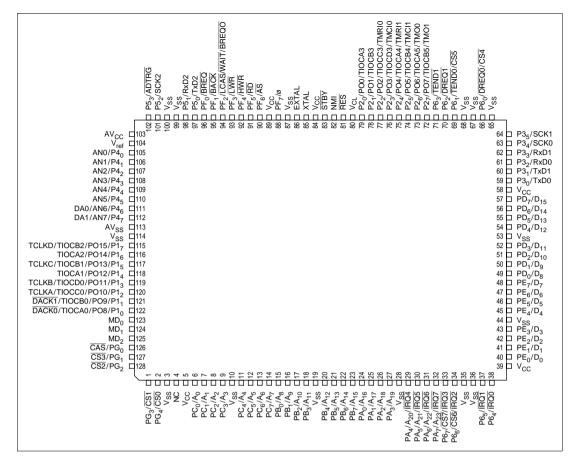


Figure 1-5 H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, H8S/2390 Pin Arrangement (FP-128: Top View)

1.3.2 Pin Functions in Each Operating Mode

Table 1-2 shows the pin functions of the H8S/2357 Series in each of the operating modes.

Table 1-2 Pin Functions in Each Operating Mode

Pin	No.	Pin Name								
TFP-120	FP-128	Mode 4*1	Mode 5*1	Mode 6	Mode 7	PROM Mode	Flash Memory Programmer Mode			
1	5	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{cc}			
2	6	A_0	A_0	PC ₀ /A ₀	PC_0	A_0	A0			
3	7	A ₁	A ₁	PC ₁ /A ₁	PC ₁	A ₁	A1			
4	8	A_2	A_2	PC ₂ /A ₂	PC ₂	A_2	A2			
5	9	A_3	A ₃	PC ₃ /A ₃	PC ₃	A ₃	A3			
6	10	V _{SS}	V _{SS}	V _{SS}	V _{ss}	V _{SS}	V _{SS}			
7	11	A ₄	A ₄	PC ₄ /A ₄	PC ₄	A ₄	A4			
8	12	A ₅	A ₅	PC ₅ /A ₅	PC ₅	A ₅	A5			
9	13	A ₆	A ₆	PC ₆ /A ₆	PC ₆	A ₆	A6			
10	14	A ₇	A ₇	PC ₇ /A ₇	PC ₇	A ₇	A7			
11	15	A ₈	A ₈	PB ₀ /A ₈	PB ₀	A ₈	A8			
12	16	A ₉	A ₉	PB ₁ /A ₉	PB ₁	ŌĒ	NC (A9)*3			
13	17	A ₁₀	A ₁₀	PB ₂ /A ₁₀	PB ₂	A ₁₀	A10			
14	18	A ₁₁	A ₁₁	PB ₃ /A ₁₁	PB ₃	A ₁₁	A11			
15	19	V _{SS}	V _{SS}	V _{ss}	V _{SS}	V _{ss}	V _{SS}			
16	20	A ₁₂	A ₁₂	PB ₄ /A ₁₂	PB ₄	A ₁₂	A12			
17	21	A ₁₃	A ₁₃	PB ₅ /A ₁₃	PB ₅	A ₁₃	A13			
18	22	A ₁₄	A ₁₄	PB ₆ /A ₁₄	PB ₆	A ₁₄	A14			
19	23	A ₁₅	A ₁₅	PB ₇ /A ₁₅	PB ₇	A ₁₅	A15			
20	24	A ₁₆	A ₁₆	PA ₀ /A ₁₆	PA_0	A ₁₆	A16			
21	25	A ₁₇	A ₁₇	PA ₁ /A ₁₇	PA ₁	V _{cc}	NC (A17)*3			
22	26	A ₁₈	A ₁₈	PA ₂ /A ₁₈	PA ₂	V _{cc}	NC (A18)*3			
23	27	A ₁₉	A ₁₉	PA ₃ /A ₁₉	PA ₃	NC	NC			
24	28	V _{ss}	V _{SS}	V _{SS}	V _{SS}	V _{ss}	V _{SS}			
25	29	A ₂₀	A ₂₀	PA ₄ /A ₂₀ / IRQ4	PA ₄ /IRQ4	NC	NC			
26	30	PA ₅ /A ₂₁ / IRQ5	PA ₅ /A ₂₁ / IRQ5	PA ₅ /A ₂₁ / IRQ5	PA ₅ /IRQ5	NC	NC			

						PROM	Flash Memory Programmer
TFP-120	FP-128	Mode 4*1	Mode 5*1	Mode 6	Mode 7	Mode	Mode
27	31	PA ₆ /A ₂₂ / IRQ6	PA ₆ /A ₂₂ / IRQ6	PA ₆ /A ₂₂ / IRQ6	PA ₆ /IRQ6	NC	NC
28	32	PA ₇ /A ₂₃ / IRQ7	PA ₇ /A ₂₃ / ĪRQ7	$\frac{PA_7/A_{23}}{IRQ7}$	PA ₇ /IRQ7	NC	NC
29	33	P6 ₇ /IRQ3/ CS7	P6 ₇ /IRQ3/ CS7	P6 ₇ /IRQ3/ CS7	P67/IRQ3	NC	NC
30	34	P6 ₆ /IRQ2/ CS6	P6 ₆ /IRQ2/ CS6	P6 ₆ /IRQ2/ CS6	P6 ₆ /IRQ2	NC	V _{cc}
_	35	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V_{SS}	V_{SS}
_	36	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}
31	37	P6 ₅ /IRQ1	P6 ₅ /IRQ1	P6₅/IRQ1	P6₅/IRQ1	NC	V _{SS}
32	38	P6 ₄ /IRQ0	P6 ₄ /IRQ0	P6 ₄ /IRQ0	P6 ₄ /IRQ0	NC	V _{SS}
33	39	V _{cc}	V _{cc}	V _{cc}	V _{CC}	V _{cc}	V _{CC}
34	40	PE ₀ /D ₀	PE ₀ /D ₀	PE ₀ /D ₀	PE ₀	NC	NC
35	41	PE ₁ /D ₁	PE ₁ /D ₁	PE ₁ /D ₁	PE ₁	NC	NC
36	42	PE ₂ /D ₂	PE ₂ /D ₂	PE ₂ /D ₂	PE ₂	NC	NC
37	43	PE ₃ /D ₃	PE ₃ /D ₃	PE ₃ /D ₃	PE ₃	NC	NC
38	44	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{ss}
39	45	PE ₄ /D ₄	PE ₄ /D ₄	PE ₄ /D ₄	PE ₄	NC	NC
40	46	PE ₅ /D ₅	PE ₅ /D ₅	PE ₅ /D ₅	PE ₅	NC	NC
41	47	PE ₆ /D ₆	PE ₆ /D ₆	PE ₆ /D ₆	PE ₆	NC	NC
42	48	PE ₇ /D ₇	PE ₇ /D ₇	PE ₇ /D ₇	PE ₇	NC	NC
43	49	D ₈	D ₈	D ₈	PD ₀	D ₀	I/O0
44	50	D ₉	D ₉	D ₉	PD ₁	D ₁	I/O1
45	51	D ₁₀	D ₁₀	D ₁₀	PD_2	D_2	I/O2
46	52	D ₁₁	D ₁₁	D ₁₁	PD_3	D_3	I/O3
47	53	V_{SS}	V_{SS}	V_{SS}	V_{SS}	V_{SS}	V_{SS}
48	54	D ₁₂	D ₁₂	D ₁₂	PD_4	D_4	I/O4
49	55	D ₁₃	D ₁₃	D ₁₃	PD ₅	D_5	I/O5
50	56	D ₁₄	D ₁₄	D ₁₄	PD_6	D_6	I/O6
51	57	D ₁₅	D ₁₅	D ₁₅	PD ₇	D ₇	I/O7
52	58	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{cc}
53	59	P3 ₀ /TxD0	P3 ₀ /TxD0	P3 ₀ /TxD0	P3 ₀ /TxD0	NC	NC
54	60	P3 ₁ /TxD1	P3 ₁ /TxD1	P3 ₁ /TxD1	P3 ₁ /TxD1	NC	NC
55	61	P3 ₂ /RxD0	P3 ₂ /RxD0	P3 ₂ /RxD0	P3 ₂ /RxD0	NC	NC (V _{CC})*3
56	62	P3 ₃ /RxD1	P3 ₃ /RxD1	P3 ₃ /RxD1	P3 ₃ /RxD1	NC	NC

TFP-	FP-					PROM	Flash Memory Programmer
120	128	Mode 4*1	Mode 5*1	Mode 6	Mode 7	Mode	Mode
57	63	P3 ₄ /SCK0	P3 ₄ /SCK0	P3 ₄ /SCK0	P3 ₄ /SCK0	NC	NC
58	64	P3 ₅ /SCK1	P3 ₅ /SCK1	P3 ₅ /SCK1	P3 ₅ /SCK1	NC	NC
59	65	V _{SS}	V _{SS}	V _{ss}	V _{SS}	V _{SS}	V _{SS}
60	66	$\frac{P6_0}{CS4}$ $\overline{DREQ0}$	$\frac{P6_0}{CS4}$ DREQ0/	$\frac{P6_0}{CS4}$ $\overline{DREQ0}$	P6 ₀ /DREQ0	NC	NC
_	67	V_{SS}	V_{SS}	V_{SS}	V_{SS}	V_{SS}	V _{SS}
_	68	V_{SS}	V_{SS}	V_{SS}	V_{SS}	V_{SS}	V_{SS}
61	69	P6 ₁ /TEND0/ CS5	P6 ₁ /TEND0/ CS5	P6 ₁ /TEND0/ CS5	P6 ₁ /TEND0	NC	NC
62	70	P6 ₂ /DREQ1	P6 ₂ /DREQ1	P6 ₂ /DREQ1	P6 ₂ /DREQ1	NC	NC
63	71	P6 ₃ /TEND1	P6 ₃ /TEND1	P6 ₃ /TEND1	P6 ₃ /TEND1	NC	NC
64	72	P2 ₇ /PO7/ TIOCB5/ TMO ₁	P2 ₇ /PO7/ TIOCB5/ TMO ₁	P2 ₇ /PO7/ TIOCB5/ TMO ₁	$P2_7/PO7/$ TIOCB5/ TMO ₁	NC	NC
65	73	P2 ₆ /PO6/ TIOCA5/ TMO ₀	NC	NC			
66	74	P2 ₅ /PO5/ TIOCB4/ TMCI	P2 ₅ /PO5/ TIOCB4/ TMCI	P2 ₅ /PO5/ ₁ TIOCB4/ TMCI ₁	P2 ₅ /PO5/ TIOCB4/ TMCI ₁	NC	V _{CC} (V _{SS})*3
67	75	P2 ₄ /PO4/ TIOCA4/ TMRI	P2 ₄ /PO4/ 1TIOCA4/ TMRI	P2 ₄ /PO4/ ₁ TIOCA4/ TMRI ₁	P2 ₄ /PO4/ TIOCA4/ TMRI ₄	NC	WE
68	76	P2 ₃ /PO3/ TIOCD3/ TMCI ₀	P2 ₃ /PO3/ TIOCD3/ TMCI ₀	P2 ₃ /PO3/ ₀ TIOCD3/ TMCI ₀	P2 ₃ /PO3/ TIOCD3/ TMCI ₀	NC	CE
69	77	P2 ₂ /PO2/ TIOCC3/ TMRI ₀	P2 ₂ /PO2/ TIOCC3/ TMRI	P2 ₂ /PO2/ ₀ TIOCC3/ TMRI ₀	P2 ₂ /PO2/ TIOCC3/ TMRI ₀	NC	ŌĒ
70	78	P2 ₁ /PO1/ TIOCB3	P2 ₁ /PO1/ TIOCB3	P2 ₁ /PO1/ TIOCB3	P2 ₁ /PO1/ TIOCB3	NC	NC
71	79	P2 ₀ /PO0/ TIOCA3	P2 ₀ /PO0/ TIOCA3	P2 ₀ /PO0/ TIOCA3	P2 ₀ /PO0/ TIOCA3	NC	NC
72	80	WDTOVF (FWE)* ² (V _{CL})* ²	WDTOVF (FWE)* ² (V _{CL})* ²	WDTOVF (FWE)* ² (V _{CL})* ²	WDTOVF (FWE)* ² (V _{CL})* ²	NC	FWE (V _{CL})* ²
73	81	RES	RES	RES	RES	V _{PP}	RES
74	82	NMI	NMI	NMI	NMI	A_9	A9 (V _{CC})*3
75	83	STBY	STBY	STBY	STBY	V _{SS}	V _{CC}
76	84	V _{CC}	V _{CC}	V _{cc}	V _{CC}	V _{cc}	V _{CC}
77	85	XTAL	XTAL	XTAL	XTAL	NC	XTAL

TFP-120	FP-128	Mode 4*1	Mode 5*1	Mode 6	Mode 7	PROM Mode	Flash Memory Programmer Mode
78	86	EXTAL	EXTAL	EXTAL	EXTAL	NC	EXTAL
79	87	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}
80	88	PF ₇ /ø	PF ₇ /ø	PF ₇ /ø	PF ₇ /ø	NC	NC
81	89	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{CC}
82	90	ĀS	ĀS	ĀS	PF ₆	NC	NC
83	91	RD	RD	RD	PF ₅	NC	NC
84	92	HWR	HWR	HWR	PF ₄	NC	NC
85	93	LWR	LWR	LWR	PF ₃	NC	NC
86	94	PF ₂ /ICAS/ WAIT/ BREQO	PF ₂ /LCAS/ WAIT/ BREQO	PF ₂ /LCAS/ WAIT/ BREQO	PF ₂	CE	NC
87	95	PF₁/BACK	PF₁/BACK	PF₁/BACK	PF ₁	PGM	NC
88	96	PF ₀ /BREQ	PF₀/BREQ	PF₀/BREQ	PF ₀	NC	NC
89	97	P5 ₀ /TxD ₂	NC	NC			
90	98	P5 ₁ /RxD ₂	NC	V _{CC} (NC)*3			
_	99	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}
_	100	V_{SS}	V_{SS}	V _{SS}	V_{SS}	V_{SS}	V _{SS}
91	101	P5 ₂ /SCK2	P5 ₂ /SCK2	P5 ₂ /SCK2	P5 ₂ /SCK2	NC	NC
92	102	P5 ₃ /ADTRG	P5 ₃ /ADTRG	P5 ₃ /ADTRG	P5 ₃ /ADTRG	NC	NC
93	103	AV _{cc}	AV _{cc}	AV _{cc}	AV _{cc}	V _{cc}	V _{cc}
94	104	V_{ref}	V_{ref}	V_{ref}	V_{ref}	V_{CC}	V _{CC}
95	105	P4 ₀ /AN0	P4 ₀ /AN0	P4 ₀ /AN0	P4 ₀ /AN0	NC	NC
96	106	P4 ₁ /AN1	P4 ₁ /AN1	P4 ₁ /AN1	P4 ₁ /AN1	NC	NC
97	107	P4 ₂ /AN2	P4 ₂ /AN2	P4 ₂ /AN2	P4 ₂ /AN2	NC	NC
98	108	P4 ₃ /AN3	P4 ₃ /AN3	P4 ₃ /AN3	P4 ₃ /AN3	NC	NC
99	109	P4 ₄ /AN4	P4 ₄ /AN4	P4 ₄ /AN4	P4 ₄ /AN4	NC	NC
100	110	P4 ₅ /AN5	P4 ₅ /AN5	P4 ₅ /AN5	P4 ₅ /AN5	NC	NC
101	111	P4 ₆ /AN6/ DA0	P4 ₆ /AN6/ DA0	P4 ₆ /AN6/ DA0	P4 ₆ /AN6/ DA0	NC	NC
102	112	P4 ₇ /AN7/ DA1	P4 ₇ /AN7/ DA1	P4 ₇ /AN7/ DA1	P4 ₇ /AN7/ DA1	NC	NC
103	113	AV _{SS}	AV _{SS}	AV _{SS}	AV _{SS}	V _{SS}	V _{SS}
104	114	V _{ss}	V _{SS}	V _{SS}	V _{SS}	V _{ss}	V _{SS}
105	115	P1 ₇ /PO15/ TIOCB2/ TCLKD	P1 ₇ /PO15/ TIOCB2/ TCLKD	P1 ₇ /PO15/ TIOCB2/ TCLKD	P1 ₇ /PO15/ TIOCB2/ TCLKD	NC	NC

TFP-120	FP-128	Mode 4*1	Mode 5*1	Mode 6	Mode 7	PROM Mode	Flash Memory Programmer Mode
106	116	P1 ₆ /PO14/ TIOCA2	P1 ₆ /PO14/ TIOCA2	P1 ₆ /PO14/ TIOCA2	P1 ₆ /PO14/ TIOCA2	NC	NC
107	117	P1 ₅ /PO13/ TIOCB1/ TCLKC	P1 ₅ /PO13/ TIOCB1/ TCLKC	P1 ₅ /PO13/ TIOCB1/ TCLKC	P1 ₅ /PO13/ TIOCB1/ TCLKC	NC	NC
108	118	P1₄/PO12/ TIOCA1	P1₄/PO12/ TIOCA1	P1₄/PO12/ TIOCA1	P1₄/PO12/ TIOCA1	NC	NC
109	119	P1 ₃ /PO11/ TIOCD0/ TCLKB	P1 ₃ /PO11/ TIOCD0/ TCLKB	P1 ₃ /PO11/ TIOCD0/ TCLKB	P1 ₃ /PO11/ TIOCD0/ TCLKB	NC	NC
110	120	P1 ₂ /PO10/ TIOCC0/ TCLKA	P1 ₂ /PO10/ TIOCC0/ TCLKA	P1 ₂ /PO10/ TIOCC0/ TCLKA	P1 ₂ /PO10/ TIOCC0/ TCLKA	NC	NC
111	121	P1 ₁ /PO9/ TIOCB0/ DACK1	P1 ₁ /PO9/ TIOCB0/ DACK1	P1 ₁ /PO9/ TIOCB0/ DACK1	P1 ₁ /PO9/ TIOCB0/ DACK1	NC	NC
112	122	P1 ₀ /PO8/ TIOCA0/ DACK0	P1 ₀ /PO8/ TIOCA0/ DACK0	P1 ₀ /PO8/ TIOCA0/ DACK0	P1 ₀ /PO8/ TIOCA0/ DACK0	NC	NC
113	123	MD_0	MD_0	MD_0	MD_0	V _{ss}	V _{ss}
114	124	MD ₁	MD ₁	MD ₁	MD ₁	V _{ss}	V _{SS}
115	125	MD_2	MD_2	MD_2	MD_2	V_{SS}	V_{SS}
116	126	PG_0/\overline{CAS}	PG_0/\overline{CAS}	PG_0/\overline{CAS}	PG_0	NC	NC
117	127	PG₁/ CS3	PG₁/CS3	PG₁/ CS3	PG ₁	NC	NC
118	128	PG ₂ /CS2	PG ₂ /CS2	PG ₂ /CS2	PG_2	NC	NC
119	1	PG ₃ /CS1	PG ₃ /CS1	PG ₃ /CS1	PG ₃	NC	NC
120	2	PG₄/CS0	PG ₄ /CS0	PG₄/CS0	PG_4	NC	NC
	3	V _{SS}	V _{SS}	V _{SS}	V_{SS}	V_{SS}	V_{SS}
_	4	NC	NC	NC	NC	NC	NC

Notes: NC pins should be connected to V_{ss} or left open.

- 1. In ROMless version, only modes 4 and 5 are available.
- 2. This pin functions as the WDTOVF pin function in ZTAT, and mask ROM products, and in the H8S/2352. In the H8S/2357F-ZTAT version, the WDTOVF pin function is not available, because this pin is used as the FWE pin. In the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390, the WDTOVF pin function is not available, because this pin is used as the V_{CL} pin.
- 3. The pin names in parentheses are available other than the H8S/2357 F-ZTAT version.

1.3.3 Pin Functions

Table 1-3 outlines the pin functions of the H8S/2357 Series.

Table 1-3 Pin Functions

		Pi	n No.			
Туре	Symbol	TFP-120	FP-128	I/O	Name and Function	
Power	V _{cc}	1, 33, 52, 76, 81	5, 39, 58, 84, 89	Input	Power supply: For connection to the power supply. All $V_{\rm CC}$ pins should be connected to the system power supply.	
	V_{ss}	6, 15, 24, 38, 47, 59, 79, 104	3, 10, 19, 28, 35, 36, 44, 53, 65, 67, 68, 87, 99, 100, 114	Input	Ground: For connection to ground (0 V). All $V_{\rm SS}$ pins should be connected to the system power supply (0 V).	
Internal voltage step-down drop pin	V _{CL} * ¹	72	80	INPUT	Connects an external capacitor between this pin and the ground pin (0 V). This pin should never be connected to $V_{\rm CC}$.	
Clock	XTAL	77	85	Input	Connects to a crystal oscillator. See section 20, Clock Pulse Generator, for typical connection diagrams for a crystal oscillator and external clock input.	
	EXTAL	78	86	Input	Connects to a crystal oscillator. The EXTAL pin can also input an external clock. See section 20, Clock Pulse Generator, for typical connection diagrams for a crystal oscillator and external clock input.	
	Ø	80	88	Output	System clock: Supplies the system clock to an external device.	

Туре	Symbol	TFP-120	FP-128	I/O	Name	and Fu	unction	
Operating mode control	MD ₂ to MD ₀	115 to 113	125 to 123	Input	Mode pins: These pins set the operating mode. The relation between the settings of pins MD_2 to MD_0 and the operating mode is shown below. These pins should not be changed while the H8S/2357 Series is operating.			
					MD_2	MD ₁	MD₀	Operating Mode
					0	0	0	_
							1	_
						1	0	_
							1	
					1	0	0	Mode 4*
							1	Mode 5*
						1	0	Mode 6
							1	Mode 7
					Note:			ersion, only 5 are available.
System control	RES	73	81	Input	Reset input: When this pin is driven low, the chip is reset. The type of reset can be selected according to the NMI input level. At power-on, the NMI pin input level should be set high.			The type of diaccording to at power-on, the
	STBY	75	83	Input	a trans		made t	oin is driven low, o hardware
	BREQ	88	96	Input	maste		ie a bus	y an external bus s request to the
	BREQO	86	94	Output	Bus request output: The external bus request signal used when an internal bus master accesses external space in the external bus-released state.			
	BACK	87	95	Output	that th		as beer	edge: Indicates n released to an

		Pin No.					
Туре	Symbol	TFP-120	FP-128	I/O	Name and Function		
System control	FWE* ²	72	80	Input	Flash write enable: Enables/disables flash memory programming.		
Interrupts	NMI	74	82	Input	Nonmaskable interrupt: Requests a nonmaskable interrupt. When this pin is not used, it should be fixed high.		
	IRQ7 to	28 to 25, 29 to 32	32 to 29, 33, 34, 37, 38	Input	Interrupt request 7 to 0: These pins request a maskable interrupt.		
Address bus	A ₂₃ to A ₀	28 to 25, 23 to 16, 14 to 7, 5 to 2	32 to 29, 27 to 20, 18 to 11, 9 to 6	Output	Address bus: These pins output an address.		
Data bus	D ₁₅ to D ₀	51 to 48, 46 to 39, 37 to 34	57 to 54, 52 to 45, 43 to 40	I/O	Data bus: These pins constitute a bidirectional data bus.		
Bus control	CS7 to CS0	29, 30, 61, 60, 117 to 12	33, 34, 69, 66, 0 127, 128, 1, 2	Output	Chip select: Signals for selecting areas 7 to 0.		
	ĀS	82	90	Output	Address strobe: When this pin is low, it indicates that address output on the address bus is enabled.		
	RD	83	91	Output	Read: When this pin is low, it indicates that the external address space can be read.		
	HWR	84	92	Output	High write/write enable: A strobe signal that writes to external space and indicates that the upper half (D ₁₅ to D ₈) of the data bus is enabled. The 2CAS type DRAM write enable signal.		
	LWR	85	93	Output	Low write: A strobe signal that writes to external space and indicates that the lower half (D ₇ to D ₀) of the data bus is enabled.		

		Pin No.			
Туре	Symbol	TFP-120	FP-128	I/O	Name and Function
Bus control	CAS	116	126	Output	Upper column address strobe/column address strobe: The 2CAS type DRAM upper column address strobe signal.
	WAIT	86	94	Input	Wait: Requests insertion of a wait state in the bus cycle when accessing external 3-state address space.
	<u>LCAS</u>	86	94	Output	Lower column address strobe: The 2- CAS type DRAM lower column address strobe signal
DMA controller (DMAC)	DREQ1, DREQ0	62, 60	70, 66	Input	DMA request 1 and 0: These pins request DMAC activation.
	TEND1, TEND0	63, 61	71, 69	Output	DMA transfer end 1 and 0: These pins indicate the end of DMAC data transfer.
	DACK1, DACK0	111, 112	121, 122	Output	DMA transfer acknowledge 1 and 0: These are the DMAC single address transfer acknowledge pins.
16-bit timer- pulse unit (TPU)	TCLKD to TCLKA	105, 107, 109, 110	115, 117, 119, 120	Input	Clock input D to A: These pins input an external clock.
	TIOCA0, TIOCB0, TIOCC0, TIOCD0	112 to 109	122 to 119	I/O	Input capture/ output compare match A0 to D0: The TGR0A to TGR0D input capture input or output compare output, or PWM output pins.
	TIOCA1, TIOCB1	108, 107	118, 117	I/O	Input capture/ output compare match A1 and B1: The TGR1A and TGR1B input capture input or output compare output, or PWM output pins.
	TIOCA2, TIOCB2	106, 105	116, 115	I/O	Input capture/ output compare match A2 and B2: The TGR2A and TGR2B input capture input or output compare output, or PWM output pins.
	TIOCA3, TIOCB3, TIOCC3, TIOCD3	71 to 68	79 to 76	I/O	Input capture/ output compare match A3 to D3: The TGR3A to TGR3D input capture input or output compare output, or PWM output pins.

		Pi	n No.		
Туре	Symbol	TFP-120	FP-128	I/O	Name and Function
16-bit timer- pulse unit (TPU)	TIOCA4, TIOCB4	67, 66	75, 74	I/O	Input capture/ output compare match A4 and B4: The TGR4A and TGR4B input capture input or output compare output, or PWM output pins.
	TIOCA5, TIOCB5	65, 64	73, 72	I/O	Input capture/ output compare match A5 and B5: The TGR5A and TGR5B input capture input or output compare output, or PWM output pins.
Programmable pulse generator (PPG)	PO15 to PO0	105 to 112, 64 to 71	115 to 122, 72 to 79	Output	Pulse output 15 to 0: Pulse output pins.
8-bit timer	TMO0, TMO1	65, 64	73, 72	Output	Compare match output: The compare match output pins.
	TMCI0, TMCI1	68, 66	76, 74	Input	Counter external clock input: Input pins for the external clock input to the counter.
	TMRI0, TMRI1	69, 67	77, 75	Input	Counter external reset input: The counter reset input pins.
Watchdog timer (WDT)	WDTOVF*	3 72	80	Output	Watchdog timer overflows: The counter overflows signal output pin in watchdog timer mode.
Serial communication interface (SCI)	TxD2, TxD1, TxD0	89, 54, 53	97, 60, 59	Output	Transmit data (channel 0, 1, 2): Data output pins.
Smart Card interface	RxD2, RxD1, RxD0	90, 56, 55	98, 62, 61	Input	Receive data (channel 0, 1, 2): Data input pins.
	SCK2, SCK1, SCK0	91, 58, 57	101, 64, 63	I/O	Serial clock (channel 0, 1, 2): Clock I/O pins.
A/D converter	AN7 to AN0	102 to 95	112 to 105	Input	Analog 7 to 0: Analog input pins.
	ADTRG	92	102	Input	A/D conversion external trigger input: Pin for input of an external trigger to start A/D conversion.
D/A converter	DA1, DA0	102, 101	112, 111	Output	Analog output: D/A converter analog output pins.

		Pi	n No.					
Туре	Symbol	TFP-120	FP-128	I/O	Name and Function			
A/D converter and D/A converter	AV _{cc}	93	103	Input	This is the power supply pin for the A/D converter and D/A converter. When the A/D converter and D/A converter are not used, this pin should be connected to the system power supply (+5 V).			
	AV _{SS}	103	113	Input	This is the ground pin for the A/D converter and D/A converter. This pin should be connected to the system power supply (0 V).			
	V_{ref}	94	104	Input	This is the reference voltage input pin for the A/D converter and D/A converter. When the A/D converter and D/A converter are not used, this pin should be connected to the system power supply (+5 V).			
I/O ports	P1 ₇ to P1 ₀	105 to 112	115 to 122	I/O	Port 1: An 8-bit I/O port. Input or output can be designated for each bit by means of the port 1 data direction register (P1DDR).			
	P2 ₇ to P2 ₀	64 to 71	72 to 79	I/O	Port 2: An 8-bit I/O port. Input or output can be designated for each bit by means of the port 2 data direction register (P2DDR).			
	P3 ₅ to P3 ₀	58 to 53	64 to 59	I/O	Port 3: A 6-bit I/O port. Input or output can be designated for each bit by means of the port 3 data direction register (P3DDR).			
	P4 ₇ to P4 ₀	102 to 95	112 to 105	Input	Port 4: An 8-bit input port.			
	P5 ₃ to P5 ₀	92 to 89	102, 101, 98, 97	I/O	Port 5: A 4-bit I/O port. Input or output can be designated for each bit by means of the port 5 data direction register (P5DDR).			

		Pi	n No.						
Туре	Symbol	TFP-120 FP-128		1/0	Name and Function				
I/O ports	P6 ₇ to P6 ₀	29 to 32, 63 to 60	33, 34, 37, 38, 71 to 69, 66	I/O	Port 6: An 8-bit I/O port. Input or output can be designated for each bit by means of the port 6 data direction register (P6DDR).				
	PA ₇ to PA ₀	28 to 25, 23 to 20	32 to 29, 27 to 24	I/O	Port A: An 8-bit I/O port. Input or output can be designated for each bit by means of the port A data direction register (PADDR).				
	PB ₇ to PB ₀	19 to 16, 14 to 11	23 to 20, 18 to 15	I/O	Port B* ⁴ : An 8-bit I/O port. Input or output can be designated for each bit by means of the port B data direction register (PBDDR).				
	PC ₇ to PC ₀	10 to 7, 5 to 2	14 to 11, 9 to 6	I/O	Port C* ⁴ : An 8-bit I/O port. Input or output can be designated for each bit by means of the port C data direction register (PCDDR).				
	PD ₇ to PD ₀	51 to 48, 46 to 43	57 to 54, 52 to 49	I/O	Port D* ⁴ : An 8-bit I/O port. Input or output can be designated for each bit by means of the port D data direction register (PDDDR).				
	PE ₇ to PE ₀	42 to 39, 37 to 34	48 to 45, 43 to 40	I/O	Port E: An 8-bit I/O port. Input or output can be designated for each bit by means of the port E data direction register (PEDDR).				
	PF ₇ to PF ₀	80, 82 to 88	88, 90 to 96	I/O	Port F: An 8-bit I/O port. Input or output can be designated for each bit by means of the port F data direction register (PFDDR).				
	PG ₄ to PG ₀	120 to 116	2, 1, 128 to 126	I/O	Port G: A 5-bit I/O port. Input or output can be designated for each bit by means of the port G data direction register (PGDDR).				

Notes: 1. Applies to the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390 only.

- 2. Applies to the H8S/2357F-ZTAT version only.
- 3. Not available in the F-ZTAT version, H8S/2398, H8S/2394, H8S/2392, H8S/2390.
- 4. Applies to the On-chip ROM version only.

Section 2 CPU

2.1 Overview

The H8S/2000 CPU is a high-speed central processing unit with an internal 32-bit architecture that is upward-compatible with the H8/300 and H8/300H CPUs. The H8S/2000 CPU has sixteen 16-bit general registers, can address a 16-Mbyte (architecturally 4-Gbyte) linear address space, and is ideal for realtime control.

2.1.1 Features

The H8S/2000 CPU has the following features.

- Upward-compatible with H8/300 and H8/300H CPUs
 - Can execute H8/300 and H8/300H object programs
- General-register architecture
 - Sixteen 16-bit general registers (also usable as sixteen 8-bit registers or eight 32-bit registers)
- Sixty-five basic instructions
 - 8/16/32-bit arithmetic and logic instructions
 - Multiply and divide instructions
 - Powerful bit-manipulation instructions
- Eight addressing modes
 - Register direct [Rn]
 - Register indirect [@ERn]
 - Register indirect with displacement [@(d:16,ERn) or @(d:32,ERn)]
 - Register indirect with post-increment or pre-decrement [@ERn+ or @-ERn]
 - Absolute address [@aa:8, @aa:16, @aa:24, or @aa:32]
 - Immediate [#xx:8, #xx:16, or #xx:32]
 - Program-counter relative [@(d:8,PC) or @(d:16,PC)]
 - Memory indirect [@@aa:8]
- 16-Mbyte address space
 - Program: 16 Mbytes
 - Data: 16 Mbytes (4 Gbytes architecturally)

High-speed operation

— All frequently-used instructions execute in one or two states

— Maximum clock rate : 20 MHz

— 8/16/32-bit register-register add/subtract : 50 ns

 -8×8 -bit register-register multiply : 600 ns

— 16 ÷ 8-bit register-register divide : 600 ns

- 16 ÷ 8-bit register-register divide : 600 ns

— 16×16 -bit register-register multiply : 1000 ns

— 32 ÷ 16-bit register-register divide : 1000 ns

CPU operating mode

- Advanced mode

Power-down state

- Transition to power-down state by SLEEP instruction
- CPU clock speed selection

2.1.2 Differences between H8S/2600 CPU and H8S/2000 CPU

The differences between the H8S/2600 CPU and the H8S/2000 CPU are as shown below.

• Register configuration

The MAC register is supported only by the H8S/2600 CPU.

MULXS.W Rs, ERd

Basic instructions

The four instructions MAC, CLRMAC, LDMAC, and STMAC are supported only by the H8S/2600 CPU.

• Number of execution states

The number of exection states of the MULXU and MULXS instructions.

Instruction	Mnemonic	H8S/2600	H8S/2000	
MULXU	MULXU.B Rs, Rd	3	12	
	MULXU.W Rs, ERd	4	20	
MULXS	MULXS.B Rs. Rd	4	13	

5

Internal Operation

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There are also differences in the address space, CCR and EXR functions, power-down state, etc., depending on the product.

2.1.3 Differences from H8/300 CPU

In comparison to the H8/300 CPU, the H8S/2000 CPU has the following enhancements.

- More general registers and control registers
 - Eight 16-bit expanded registers, and one 8-bit control register, have been added.
- Expanded address space
 - Advanced mode supports a maximum 16-Mbyte address space.
- Enhanced addressing
 - The addressing modes have been enhanced to make effective use of the 16-Mbyte address space.
- Enhanced instructions
 - Addressing modes of bit-manipulation instructions have been enhanced.
 - Signed multiply and divide instructions have been added.
 - Two-bit shift instructions have been added.
 - Instructions for saving and restoring multiple registers have been added.
 - A test and set instruction has been added.
- Higher speed
 - Basic instructions execute twice as fast.

2.1.4 Differences from H8/300H CPU

In comparison to the H8/300H CPU, the H8S/2000 CPU has the following enhancements.

- Additional control register
 - One 8-bit control register has been added.
- Enhanced instructions
 - Addressing modes of bit-manipulation instructions have been enhanced.
 - Two-bit shift instructions have been added.
 - Instructions for saving and restoring multiple registers have been added.
 - A test and set instruction has been added.
- Higher speed
 - Basic instructions execute twice as fast.

2.2 **CPU Operating Modes**

The H8S/2357 Series CPU has advanced operating mode. Advanced mode supports a maximum 16-Mbyte total address space (architecturally a maximum 16-Mbyte program area and a maximum of 4 Gbytes for program and data areas combined). The mode is selected by the mode pins of the microcontroller.

Advanced Mode

Address Space: Linear access is provided to a 16-Mbyte maximum address space (architecturally a maximum 16-Mbyte program area and a maximum 4-Gbyte data area, with a maximum of 4 Gbytes for program and data areas combined).

Extended Registers (En): The extended registers (E0 to E7) can be used as 16-bit registers, or as the upper 16-bit segments of 32-bit registers or address registers.

Instruction Set: All instructions and addressing modes can be used.

Exception Vector Table and Memory Indirect Branch Addresses: In advanced mode the top area starting at H'00000000 is allocated to the exception vector table in units of 32 bits. In each 32 bits, the upper 8 bits are ignored and a branch address is stored in the lower 24 bits (figure 2-1). For details of the exception vector table, see section 4, Exception Handling.

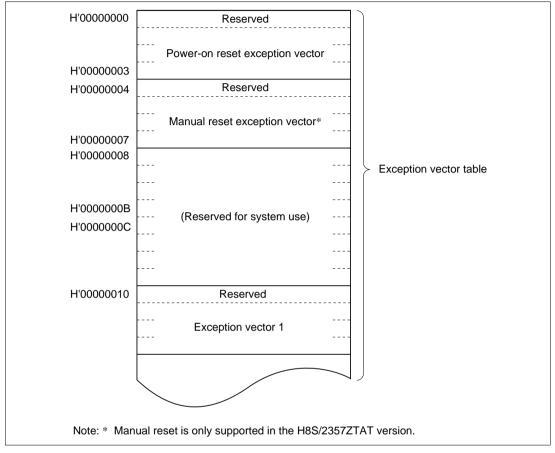


Figure 2-1 Exception Vector Table (Advanced Mode)

The memory indirect addressing mode (@@aa:8) employed in the JMP and JSR instructions uses an 8-bit absolute address included in the instruction code to specify a memory operand that contains a branch address. In advanced mode the operand is a 32-bit longword operand, providing a 32-bit branch address. The upper 8 bits of these 32 bits are a reserved area that is regarded as H'00. Branch addresses can be stored in the area from H'00000000 to H'000000FF. Note that the first part of this range is also the exception vector table.

Stack Structure: In advanced mode, when the program counter (PC) is pushed onto the stack in a subroutine call, and the PC, condition-code register (CCR), and extended control register (EXR) are pushed onto the stack in exception handling, they are stored as shown in figure 2-2. When EXR is invalid, it is not pushed onto the stack. For details, see section 4, Exception Handling.

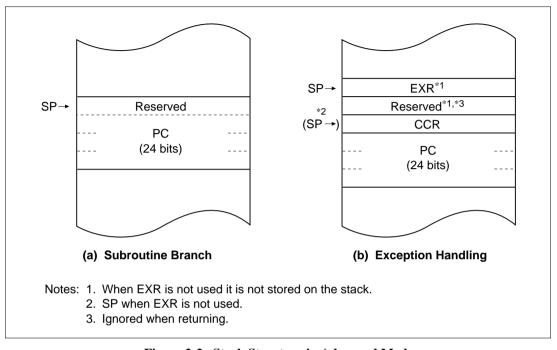


Figure 2-2 Stack Structure in Advanced Mode

2.3 Address Space

Figure 2-3 shows a memory map of the H8S/2000 CPU. The H8S/2000 CPU provides linear access to a maximum 16-Mbyte (architecturally 4-Gbyte) address space in advanced mode.

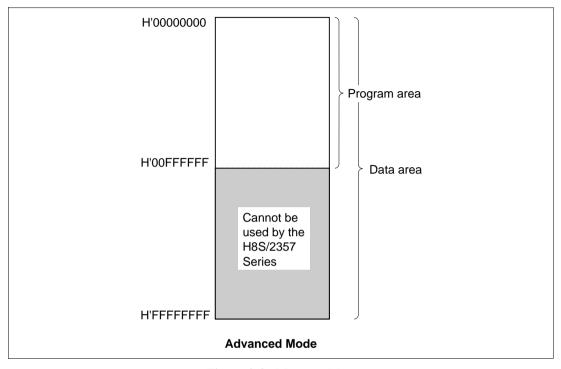


Figure 2-3 Memory Map

2.4 Register Configuration

2.4.1 Overview

The CPU has the internal registers shown in figure 2-4. There are two types of registers: general registers and control registers.

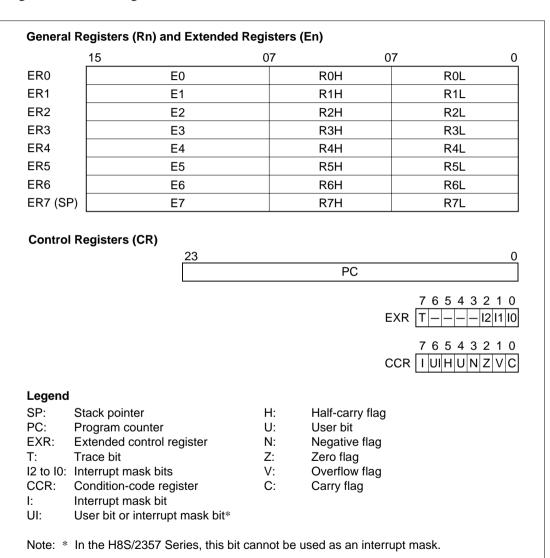


Figure 2-4 CPU Registers

2.4.2 General Registers

The CPU has eight 32-bit general registers. These general registers are all functionally alike and can be used as both address registers and data registers. When a general register is used as a data register, it can be accessed as a 32-bit, 16-bit, or 8-bit register. When the general registers are used as 32-bit registers or address registers, they are designated by the letters ER (ER0 to ER7).

The ER registers divide into 16-bit general registers designated by the letters E (E0 to E7) and R (R0 to R7). These registers are functionally equivalent, providing a maximum sixteen 16-bit registers. The E registers (E0 to E7) are also referred to as extended registers.

The R registers divide into 8-bit general registers designated by the letters RH (R0H to R7H) and RL (R0L to R7L). These registers are functionally equivalent, providing a maximum sixteen 8-bit registers.

Figure 2-5 illustrates the usage of the general registers. The usage of each register can be selected independently.

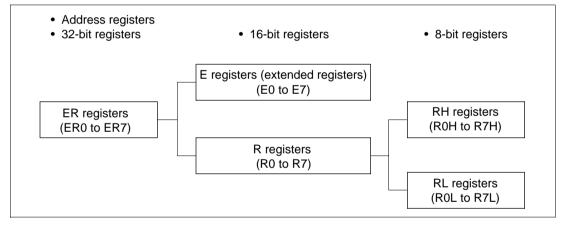


Figure 2-5 Usage of General Registers

General register ER7 has the function of stack pointer (SP) in addition to its general-register function, and is used implicitly in exception handling and subroutine calls. Figure 2-6 shows the stack.

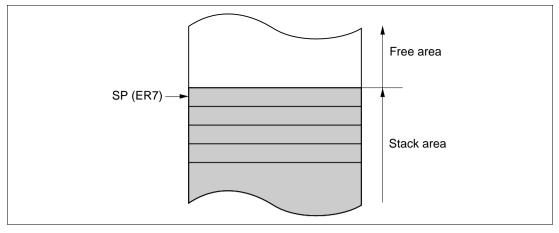


Figure 2-6 Stack

2.4.3 Control Registers

The control registers are the 24-bit program counter (PC), 8-bit extended control register (EXR), and 8-bit condition-code register (CCR).

- (1) **Program Counter (PC):** This 24-bit counter indicates the address of the next instruction the CPU will execute. The length of all CPU instructions is 2 bytes (one word), so the least significant PC bit is ignored. (When an instruction is fetched, the least significant PC bit is regarded as 0.)
- (2) Extended Control Register (EXR): This 8-bit register contains the trace bit (T) and three interrupt mask bits (I2 to I0).

Bit 7—Trace Bit (T): Selects trace mode. When this bit is cleared to 0, instructions are executed in sequence. When this bit is set to 1, a trace exception is generated each time an instruction is executed.

Bits 6 to 3—Reserved: These bits are reserved. They are always read as 1.

Bits 2 to 0—Interrupt Mask Bits (I2 to I0): These bits designate the interrupt mask level (0 to 7). For details, refer to section 5, Interrupt Controller.

Operations can be performed on the EXR bits by the LDC, STC, ANDC, ORC, and XORC instructions. All interrupts, including NMI, are disabled for three states after one of these instructions is executed, except for STC.

(3) Condition-Code Register (CCR): This 8-bit register contains internal CPU status information, including an interrupt mask bit (I) and half-carry (H), negative (N), zero (Z), overflow (V), and carry (C) flags.

Bit 7—Interrupt Mask Bit (I): Masks interrupts other than NMI when set to 1. (NMI is accepted regardless of the I bit setting.) The I bit is set to 1 by hardware at the start of an exception-handling sequence. For details, refer to section 5, Interrupt Controller.

Bit 6—User Bit or Interrupt Mask Bit (UI): Can be written and read by software using the LDC, STC, ANDC, ORC, and XORC instructions. With the H8S/2357 Series, this bit cannot be used as an interrupt mask bit.

Bit 5—Half-Carry Flag (H): When the ADD.B, ADDX.B, SUB.B, SUBX.B, CMP.B, or NEG.B instruction is executed, this flag is set to 1 if there is a carry or borrow at bit 3, and cleared to 0 otherwise. When the ADD.W, SUB.W, CMP.W, or NEG.W instruction is executed, the H flag is set to 1 if there is a carry or borrow at bit 11, and cleared to 0 otherwise. When the ADD.L, SUB.L, CMP.L, or NEG.L instruction is executed, the H flag is set to 1 if there is a carry or borrow at bit 27, and cleared to 0 otherwise.

Bit 4—User Bit (U): Can be written and read by software using the LDC, STC, ANDC, ORC, and XORC instructions.

Bit 3—Negative Flag (N): Stores the value of the most significant bit (sign bit) of data.

Bit 2—Zero Flag (Z): Set to 1 to indicate zero data, and cleared to 0 to indicate non-zero data.

Bit 1—Overflow Flag (V): Set to 1 when an arithmetic overflow occurs, and cleared to 0 at other times.

Bit 0—Carry Flag (C): Set to 1 when a carry occurs, and cleared to 0 otherwise. Used by:

- Add instructions, to indicate a carry
- Subtract instructions, to indicate a borrow
- Shift and rotate instructions, to store the value shifted out of the end bit

The carry flag is also used as a bit accumulator by bit manipulation instructions.

Some instructions leave some or all of the flag bits unchanged. For the action of each instruction on the flag bits, refer to Appendix A.1, List of Instructions.

Operations can be performed on the CCR bits by the LDC, STC, ANDC, ORC, and XORC instructions. The N, Z, V, and C flags are used as branching conditions for conditional branch (Bcc) instructions.

2.4.4 Initial Register Values

Reset exception handling loads the CPU's program counter (PC) from the vector table, clears the trace bit in EXR to 0, and sets the interrupt mask bits in CCR and EXR to 1. The other CCR bits and the general registers are not initialized. In particular, the stack pointer (ER7) is not initialized.

The stack pointer should therefore be initialized by an MOV.L instruction executed immediately after a reset.

2.5 Data Formats

The CPU can process 1-bit, 4-bit (BCD), 8-bit (byte), 16-bit (word), and 32-bit (longword) data. Bit-manipulation instructions operate on 1-bit data by accessing bit n (n = 0, 1, 2, ..., 7) of byte operand data. The DAA and DAS decimal-adjust instructions treat byte data as two digits of 4-bit BCD data.

2.5.1 General Register Data Formats

Figure 2-7 shows the data formats in general registers.

Data Type	Register Number	Data Format
1-bit data	RnH	7 0 7 6 5 4 3 2 1 0 Don't care
1-bit data	RnL	7 0 Don't care 7 6 5 4 3 2 1 0
4-bit BCD data	RnH	7 4 3 0 Upper Lower Don't care
4-bit BCD data	RnL	7 4 3 0 Don't care Upper Lower
Byte data	RnH	7 0 Don't care MSB LSB
Byte data	RnL	7 0 Don't care MSB LSB

Figure 2-7 General Register Data Formats

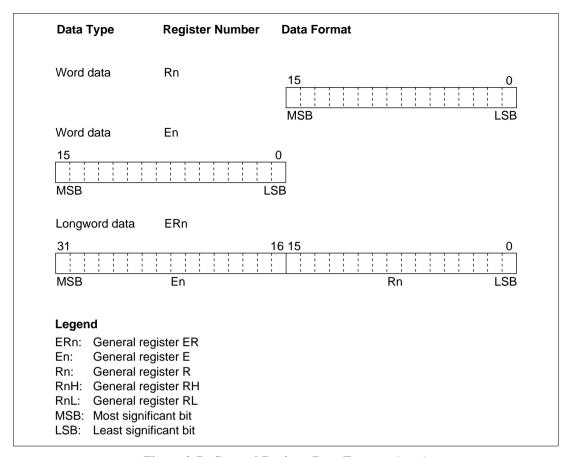


Figure 2-7 General Register Data Formats (cont)

2.5.2 Memory Data Formats

Figure 2-8 shows the data formats in memory. The CPU can access word data and longword data in memory, but word or longword data must begin at an even address. If an attempt is made to access word or longword data at an odd address, no address error occurs but the least significant bit of the address is regarded as 0, so the access starts at the preceding address. This also applies to instruction fetches.

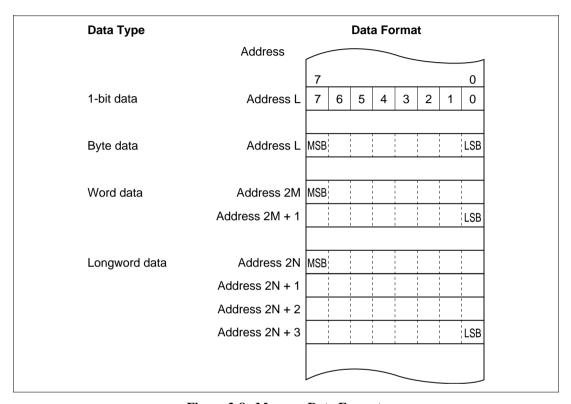


Figure 2-8 Memory Data Formats

When ER7 is used as an address register to access the stack, the operand size should be word size or longword size.

2.6 Instruction Set

2.6.1 Overview

The H8S/2000 CPU has 65 types of instructions. The instructions are classified by function in table 2-1.

Table 2-1 Instruction Classification

Function	Instructions	Size	Types	
Data transfer	MOV	BWL	5	
	POP* ¹ , PUSH* ¹	WL	_	
	LDM, STM	L		
	MOVFPE, MOVTPE*3	В	_	
Arithmetic	ADD, SUB, CMP, NEG	BWL	19	
operations	ADDX, SUBX, DAA, DAS	В		
	INC, DEC	BWL		
	ADDS, SUBS	L		
	MULXU, DIVXU, MULXS, DIVXS	BW		
	EXTU, EXTS	WL		
	TAS* ⁴	В		
Logic operations	AND, OR, XOR, NOT	BWL	4	
Shift	SHAL, SHAR, SHLL, SHLR, ROTL, ROTR, ROTXL, ROTXR	BWL	8	
Bit manipulation	BSET, BCLR, BNOT, BTST, BLD, BILD, BST, BIST, BAND, BIAND, BOR, BIOR, BXOR, BIXOR	В	14	
Branch	Bcc*2, JMP, BSR, JSR, RTS	_	5	
System control	TRAPA, RTE, SLEEP, LDC, STC, ANDC, ORC, XORC, NOP	_	9	
Block data transfer	_	1		

Notes: B-byte size; W-word size; L-longword size.

- POP.W Rn and PUSH.W Rn are identical to MOV.W @SP+, Rn and MOV.W Rn, @-SP. POP.L ERn and PUSH.L ERn are identical to MOV.L @SP+, ERn and MOV.L ERn, @-SP.
- 2. Bcc is the general name for conditional branch instructions.
- 3. Cannot be used in the H8S/2357 Series.
- 4. Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction.

2.6.2 Instructions and Addressing Modes

Table 2-2 indicates the combinations of instructions and addressing modes that the H8S/2600 CPU can use.

Table 2-2 Combinations of Instructions and Addressing Modes

		Addressing Modes													
Function	Instruction	××#	Rn	@ERn	@(d:16,ERn)	@(d:32,ERn)	@-ERn/@ERn+	@aa:8	@aa:16	@aa:24	@aa:32	@(d:8,PC)	@(d:16,PC)	@ @aa:8	1
Data	MOV	BWL	BWL	BWL	BWL	BWL	BWL	В	BWL	_	BWL	_	_	_	_
transfer	POP, PUSH	_	_	_	_	_	_	_	_	_	_	_	_	_	WL
	LDM, STM	_	_	_	_	_	_	_	_	_	_	_	_	_	L
	MOVFPE, MOVTPE*1	_	_	_	_	_	_	_	В	_	_	_		_	
	ADD, CMP	BWL	BWL	_	_	_	_	_	_	_	_	_	_	_	_
	SUB	WL	BWL	_	_	_	_	_	_	_	_	_	_	_	-
	ADDX, SUBX	В	В	_	_	_	_	_	_	_	_	_	_	_	_
	ADDS, SUBS	_	L	_	_	_	_	_	_	_	_	_	_	_	_
	INC, DEC	_	BWL	_	_	_	_	_	_	_	_	_	_	_	_
	DAA, DAS	_	В	_	_	_	_	_	_	_	_	_	_	_	_
	MULXU, DIVXU	-	BW	_	-	_	_	_	_	_	_	_	_	-	-
	MULXS, DIVXS	-	BW	_	_	_	_	_	_	_	_	_	_	_	_
	NEG	_	BWL	_	_	_	_	_	_	_	_	_	_	_	_
	EXTU, EXTS	_	WL	_	_	_	_	_	_	_	_	_	_	_	_
	TAS*2	_	_	В	_	_	_	_	_	_	_	_	_	_	_
	AND, OR, XOR	BWL	BWL	_	_	_	_	_	_	_	_	_	_	_	_
	NOT	_	BWL	_	_	_	_	_	_	_	_	_	_	_	_
Shift	•	_	BWL	_	_	_	_	_	_	_	_	_	_	_	_
Bit manipula	tion	_	В	В	_	_	_	В	В	_	В	_	_	_	_
Branch	Bcc, BSR	_	_	_	_	_	_	_	_	_	_	0	0	_	_
	JMP, JSR	_	_	_	_	_	_	_	_	0	_	_	_	0	_
	RTS	_	_	_	_	_	_	_	_	_	_	_	_	_	0
System	TRAPA	_	_	_	_	_	_	_	_	_	_	_	_	_	0
Shift Bit manipulati Branch System	RTE	_	_	_	_	_	_	_	_	_	_	_	_	_	0
	SLEEP	_	_	_	_	_	_	_	_	_	_	_	_	_	0
	LDC	В	В	w	w	w	w	_	w	_	w	_	_	_	_
	STC	_	В	w	w	w	w	_	w	_	w	_	_	_	_
	ANDC, ORC, XORC	В	_	_	-	_	_	_	_	_	_	_	-	-	-
	NOP	_	_	_	_	_	_	_	_	_	_	_	_	_	0
Block data tr	ansfer	_	_	_	_	_	_	_	_	_	_	_	_	_	BW

Legend

B: Byte

W: Word L: Longword

Notes: 1. Cannot be used in the H8S/2357 Series.

2. Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction.

2.6.3 Table of Instructions Classified by Function

Table 2-3 summarizes the instructions in each functional category. The notation used in table 2-3 is defined below.

Operation Notation

Rd	General register (destination)*
Rs	General register (source)*
Rn	General register*
ERn	General register (32-bit register)
(EAd)	Destination operand
(EAs)	Source operand
EXR	Extended control register
CCR	Condition-code register
N	N (negative) flag in CCR
Z	Z (zero) flag in CCR
V	V (overflow) flag in CCR
С	C (carry) flag in CCR
PC	Program counter
SP	Stack pointer
#IMM	Immediate data
disp	Displacement
+	Addition
_	Subtraction
×	Multiplication
÷	Division
۸	Logical AND
V	Logical OR
\oplus	Logical exclusive OR
\rightarrow	Move
_	NOT (logical complement)
:8/:16/:24/:32	8-, 16-, 24-, or 32-bit length
	<u> </u>

Note: * General registers include 8-bit registers (R0H to R7H, R0L to R7L), 16-bit registers (R0 to R7, E0 to E7), and 32-bit registers (ER0 to ER7).

 Table 2-3
 Instructions Classified by Function

Туре	Instruction	Size*1	Function
Data transfer	MOV	B/W/L	$(EAs) \rightarrow Rd, Rs \rightarrow (Ead)$ Moves data between two general registers or between a general register and memory, or moves immediate data to a general register.
	MOVFPE	В	Cannot be used in the H8S/2357 Series.
	MOVTPE	В	Cannot be used in the H8S/2357 Series.
	POP	W/L	@SP+ \rightarrow Rn Pops a register from the stack. POP.W Rn is identical to MOV.W @SP+, Rn. POP.L ERn is identical to MOV.L @SP+, ERn.
	PUSH	W/L	$Rn \rightarrow @-SP$ Pushes a register onto the stack. PUSH.W Rn is identical to MOV.W Rn, @-SP. PUSH.L ERn is identical to MOV.L ERn, @-SP.
	LDM	L	$@$ SP+ \rightarrow Rn (register list) Pops two or more general registers from the stack.
	STM	L	Rn (register list) \rightarrow @-SP Pushes two or more general registers onto the stack.

Туре	Instruction	Size*1	Function
Arithmetic operations	ADD SUB	B/W/L	Rd \pm Rs \rightarrow Rd, Rd \pm #IMM \rightarrow Rd Performs addition or subtraction on data in two general registers, or on immediate data and data in a general register. (Immediate byte data cannot be subtracted from byte data in a general register. Use the SUBX or ADD instruction.)
	ADDX SUBX	В	Rd \pm Rs \pm C \rightarrow Rd, Rd \pm #IMM \pm C \rightarrow Rd Performs addition or subtraction with carry or borrow on byte data in two general registers, or on immediate data and data in a general register.
	INC DEC	B/W/L	Rd \pm 1 \rightarrow Rd, Rd \pm 2 \rightarrow Rd Increments or decrements a general register by 1 or 2. (Byte operands can be incremented or decremented by 1 only.)
	ADDS SUBS	L	Rd \pm 1 \rightarrow Rd, Rd \pm 2 \rightarrow Rd, Rd \pm 4 \rightarrow Rd Adds or subtracts the value 1, 2, or 4 to or from data in a 32-bit register.
	DAA DAS	В	Rd decimal adjust → Rd Decimal-adjusts an addition or subtraction result in a general register by referring to the CCR to produce 4-bit BCD data.
	MULXU	B/W	$Rd \times Rs \rightarrow Rd$ Performs unsigned multiplication on data in two general registers: either 8 bits \times 8 bits \rightarrow 16 bits or 16 bits \times 16 bits \rightarrow 32 bits.
	MULXS	B/W	$Rd \times Rs \rightarrow Rd$ Performs signed multiplication on data in two general registers: either 8 bits \times 8 bits \rightarrow 16 bits or 16 bits \times 16 bits \rightarrow 32 bits.
	DIVXU	B/W	Rd \div Rs \rightarrow Rd Performs unsigned division on data in two general registers: either 16 bits \div 8 bits \rightarrow 8-bit quotient and 8-bit remainder or 32 bits \div 16 bits \rightarrow 16-bit quotient and 16- bit remainder.

Туре	Instruction	Size*1	Function
Arithmetic operations	DIVXS	B/W	Rd \div Rs \rightarrow Rd Performs signed division on data in two general registers: either 16 bits \div 8 bits \rightarrow 8-bit quotient and 8-bit remainder or 32 bits \div 16 bits \rightarrow 16-bit quotient and 16- bit remainder.
	СМР	B/W/L	Rd – Rs, Rd – #IMM Compares data in a general register with data in another general register or with immediate data, and sets CCR bits according to the result.
	NEG	B/W/L	$0-Rd \rightarrow Rd$ Takes the two's complement (arithmetic complement) of data in a general register.
	EXTU	W/L	Rd (zero extension) → Rd Extends the lower 8 bits of a 16-bit register to word size, or the lower 16 bits of a 32-bit register to longword size, by padding with zeros on the left.
	EXTS	W/L	Rd (sign extension) → Rd Extends the lower 8 bits of a 16-bit register to word size, or the lower 16 bits of a 32-bit register to longword size, by extending the sign bit.
	TAS	В	@ERd – 0, 1 \rightarrow (<bit 7=""> of @ERd)*² Tests memory contents, and sets the most significant bit (bit 7) to 1.</bit>

Туре	Instruction	Size*1	Function
Logic operations	AND	B/W/L	$Rd \wedge Rs \rightarrow Rd$, $Rd \wedge \#IMM \rightarrow Rd$ Performs a logical AND operation on a general register and another general register or immediate data.
	OR	B/W/L	Rd ∨ Rs → Rd, Rd ∨ #IMM → Rd Performs a logical OR operation on a general register and another general register or immediate data.
	XOR	B/W/L	$Rd \oplus Rs \rightarrow Rd$, $Rd \oplus \#IMM \rightarrow Rd$ Performs a logical exclusive OR operation on a general register and another general register or immediate data.
	NOT	B/W/L	\neg (Rd) \rightarrow (Rd) Takes the one's complement of general register contents.
Shift operations	SHAL SHAR	B/W/L	Rd (shift) → Rd Performs an arithmetic shift on general register contents. 1-bit or 2-bit shift is possible.
	SHLL SHLR	B/W/L	Rd (shift) → Rd Performs a logical shift on general register contents. 1-bit or 2-bit shift is possible.
	ROTL ROTR	B/W/L	Rd (rotate) → Rd Rotates general register contents. 1-bit or 2-bit rotation is possible.
	ROTXL ROTXR	B/W/L	Rd (rotate) \rightarrow Rd Rotates general register contents through the carry flag. 1-bit or 2-bit rotation is possible.

Туре	Instruction	Size*1	Function
Bit- manipulation instructions	BSET	В	1 → (<bit>bit-No.> of <ead>) Sets a specified bit in a general register or memory operand to 1. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit>
	BCLR	В	0 → (<bith>bit-No.> of <ead>) Clears a specified bit in a general register or memory operand to 0. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bith>
	BNOT	В	¬ (<bit-no.> of <ead>) \rightarrow (<bit-no.> of <ead>) Inverts a specified bit in a general register or memory operand. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit-no.></ead></bit-no.>
	BTST	В	¬ (<bit-no.> of <ead>) → Z Tests a specified bit in a general register or memory operand and sets or clears the Z flag accordingly. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit-no.>
	BAND	В	$C \land (\mbox{\rm circ} No.\mbox{\rm of } \mbox{\rm EAd>}) \to C$ ANDs the carry flag with a specified bit in a general register or memory operand and stores the result in the carry flag.
	BIAND	В	$C \land \neg$ (<bit-no.> of <ead>) $\rightarrow C$ ANDs the carry flag with the inverse of a specified bit in a general register or memory operand and stores the result in the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
	BOR	В	$C \lor (\text{-bit-No.} \gt \text{of } \text{-EAd} \gt) \to C$ ORs the carry flag with a specified bit in a general register or memory operand and stores the result in the carry flag.
	BIOR	В	$\text{C} \vee \neg \text{ (of)} \rightarrow \text{C}$ ORs the carry flag with the inverse of a specified bit in a general register or memory operand and stores the result in the carry flag. The bit number is specified by 3-bit immediate data.

Туре	Instruction	Size*1	Function
Bit- manipulation instructions	BXOR	В	$C \oplus (\text{-bit-No} \text{ of } \text{-EAd}) \to C$ Exclusive-ORs the carry flag with a specified bit in a general register or memory operand and stores the result in the carry flag.
	BIXOR	В	$C \oplus \neg$ (<bit-no.> of <ead>) $\rightarrow C$ Exclusive-ORs the carry flag with the inverse of a specified bit in a general register or memory operand and stores the result in the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
	BLD	В	(<bit-no.> of <ead>) \rightarrow C Transfers a specified bit in a general register or memory operand to the carry flag.</ead></bit-no.>
	BILD	В	\neg (<bit-no.> of <ead>) \rightarrow C Transfers the inverse of a specified bit in a general register or memory operand to the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
	BST	В	C → (<bit-no.> of <ead>) Transfers the carry flag value to a specified bit in a general register or memory operand.</ead></bit-no.>
	BIST	В	\neg C \rightarrow (bit-No.> of <ead>) Transfers the inverse of the carry flag value to a specified bit in a general register or memory operand. The bit number is specified by 3-bit immediate data.</ead>

Туре	Instruction	Size*1	Function		
Branch instructions	Всс	_	Branches to a specified address if a specified condition is true. The branching conditions are listed below.		
			Mnemonic	Description	Condition
			BRA(BT)	Always (true)	Always
			BRN(BF)	Never (false)	Never
			BHI	High	C ∨ Z = 0
			BLS	Low or same	C ∨ Z = 1
			BCC(BHS)	Carry clear (high or same)	C = 0
			BCS(BLO)	Carry set (low)	C = 1
			BNE	Not equal	Z = 0
			BEQ	Equal	Z = 1
			BVC	Overflow clear	V = 0
			BVS	Overflow set	V = 1
			BPL	Plus	N = 0
			BMI	Minus	N = 1
			BGE	Greater or equal	N ⊕ V = 0
			BLT	Less than	N ⊕ V = 1
			BGT	Greater than	$Z\lor(N\oplus V)=0$
			BLE	Less or equal	$Z\lor(N\oplus V)=1$
	JMP	_	Branches unco	nditionally to a specified	I address.
	BSR	_	Branches to a subroutine at a specified address.		
	JSR	_	Branches to a	subroutine at a specified	l address.
	RTS	_	Returns from a	subroutine	

Туре	Instruction	Size*1	Function
System control	TRAPA	_	Starts trap-instruction exception handling.
instructions	RTE	_	Returns from an exception-handling routine.
	SLEEP	_	Causes a transition to a power-down state.
	LDC	B/W	(EAs) → CCR, (EAs) → EXR Moves the source operand contents or immediate data to CCR or EXR. Although CCR and EXR are 8-bit registers, word-size transfers are performed between them and memory. The upper 8 bits are valid.
	STC	B/W	CCR → (EAd), EXR → (EAd) Transfers CCR or EXR contents to a general register or memory. Although CCR and EXR are 8-bit registers, word-size transfers are performed between them and memory. The upper 8 bits are valid.
	ANDC	В	CCR \land #IMM \rightarrow CCR, EXR \land #IMM \rightarrow EXR Logically ANDs the CCR or EXR contents with immediate data.
	ORC	В	CCR \vee #IMM \rightarrow CCR, EXR \vee #IMM \rightarrow EXR Logically ORs the CCR or EXR contents with immediate data.
	XORC	В	CCR \oplus #IMM \rightarrow CCR, EXR \oplus #IMM \rightarrow EXR Logically exclusive-ORs the CCR or EXR contents with immediate data.
	NOP	_	$PC + 2 \rightarrow PC$ Only increments the program counter.

Туре	Instruction	Size*1	Function
Block data transfer instruction	EEPMOV.B	_	if R4L 0 then Repeat @ER5+ \rightarrow @ER6+ R4L-1 \rightarrow R4L Until R4L = 0 else next;
	EEPMOV.W	_	if R4 0 then Repeat @ER5+ \rightarrow @ER6+ R4-1 \rightarrow R4 Until R4 = 0 else next;
			Transfers a data block according to parameters set in general registers R4L or R4, ER5, and ER6.
			R4L or R4: size of block (bytes) ER5: starting source address ER6: starting destination address
			Execution of the next instruction begins as soon as the transfer is completed.

Notes: 1. Size refers to the operand size.

B: Byte W: Word L: Longword

2. Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction.

2.6.4 Basic Instruction Formats

The CPU instructions consist of 2-byte (1-word) units. An instruction consists of an operation field (op field), a register field (r field), an effective address extension (EA field), and a condition field (cc).

Figure 2-9 shows examples of instruction formats.

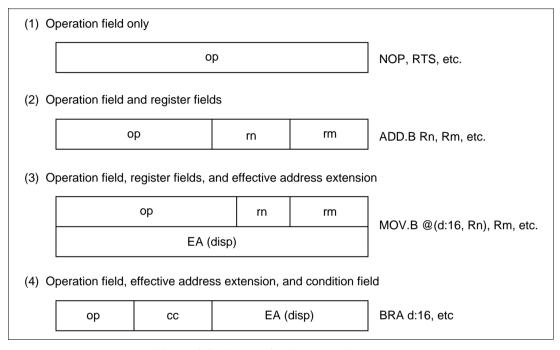


Figure 2-9 Instruction Formats (Examples)

- (1) **Operation Field:** Indicates the function of the instruction, the addressing mode, and the operation to be carried out on the operand. The operation field always includes the first four bits of the instruction. Some instructions have two operation fields.
- (2) **Register Field:** Specifies a general register. Address registers are specified by 3 bits, data registers by 3 bits or 4 bits. Some instructions have two register fields. Some have no register field.
- (3) Effective Address Extension: Eight, 16, or 32 bits specifying immediate data, an absolute address, or a displacement.
- (4) Condition Field: Specifies the branching condition of Bcc instructions.

2.7 Addressing Modes and Effective Address Calculation

2.7.1 Addressing Mode

The CPU supports the eight addressing modes listed in table 2-4. Each instruction uses a subset of these addressing modes. Arithmetic and logic instructions can use the register direct and immediate modes. Data transfer instructions can use all addressing modes except program-counter relative and memory indirect. Bit manipulation instructions use register direct, register indirect, or absolute addressing mode to specify an operand, and register direct (BSET, BCLR, BNOT, and BTST instructions) or immediate (3-bit) addressing mode to specify a bit number in the operand.

Table 2-4 Addressing Modes

No.	Addressing Mode	Symbol
1	Register direct	Rn
2	Register indirect	@ERn
3	Register indirect with displacement	@(d:16,ERn)/@(d:32,ERn)
4	Register indirect with post-increment Register indirect with pre-decrement	@ERn+ @-ERn
5	Absolute address	@aa:8/@aa:16/@aa:24/@aa:32
6	Immediate	#xx:8/#xx:16/#xx:32
7	Program-counter relative	@(d:8,PC)/@(d:16,PC)
8	Memory indirect	@@aa:8

- (1) **Register Direct—Rn:** The register field of the instruction specifies an 8-, 16-, or 32-bit general register containing the operand. R0H to R7H and R0L to R7L can be specified as 8-bit registers. R0 to R7 and E0 to E7 can be specified as 16-bit registers. ER0 to ER7 can be specified as 32-bit registers.
- (2) **Register Indirect**—@**ERn:** The register field of the instruction code specifies an address register (ERn) which contains the address of the operand on memory. If the address is a program instruction address, the lower 24 bits are valid and the upper 8 bits are all assumed to be 0 (H'00).
- (3) Register Indirect with Displacement—@(d:16, ERn) or @(d:32, ERn): A 16-bit or 32-bit displacement contained in the instruction is added to an address register (ERn) specified by the register field of the instruction, and the sum gives the address of a memory operand. A 16-bit displacement is sign-extended when added.

(4) Register Indirect with Post-Increment or Pre-Decrement—@ERn+ or @-ERn:

- Register indirect with post-increment—@ERn+

 The register field of the instruction code specifies an address register (ERn) which contains the address of a memory operand. After the operand is accessed, 1, 2, or 4 is added to the address register contents and the sum is stored in the address register. The value added is 1 for byte access, 2 for word transfer instruction, or 4 for longword transfer instruction. For word or longword transfer instruction, the register value should be even.
- Register indirect with pre-decrement—@-ERn

 The value 1, 2, or 4 is subtracted from an address register (ERn) specified by the register field in the instruction code, and the result becomes the address of a memory operand. The result is also stored in the address register. The value subtracted is 1 for byte access, 2 for word transfer instruction, or 4 for longword transfer instruction. For word or longword transfer instruction, the register value should be even.
- (5) Absolute Address—@aa:8, @aa:16, @aa:24, or @aa:32: The instruction code contains the absolute address of a memory operand. The absolute address may be 8 bits long (@aa:8), 16 bits long (@aa:16), 24 bits long (@aa:24), or 32 bits long (@aa:32).

To access data, the absolute address should be 8 bits (@aa:8), 16 bits (@aa:16), or 32 bits (@aa:32) long. For an 8-bit absolute address, the upper 24 bits are all assumed to be 1 (H'FFFF). For a 16-bit absolute address the upper 16 bits are a sign extension. A 32-bit absolute address can access the entire address space.

A 24-bit absolute address (@aa:24) indicates the address of a program instruction. The upper 8 bits are all assumed to be 0 (H'00).

Table 2-5 indicates the accessible absolute address ranges.

Table 2-5 Absolute Address Access Ranges

Absolute Address		Advanced Mode
Data address	8 bits (@aa:8)	H'FFFF00 to H'FFFFFF
	16 bits (@aa:16)	H'000000 to H'007FFF, H'FF8000 to H'FFFFFF
	32 bits (@aa:32)	H'000000 to H'FFFFF
Program instruction address	24 bits (@aa:24)	

(6) Immediate—#xx:8, #xx:16, or #xx:32: The instruction contains 8-bit (#xx:8), 16-bit (#xx:16), or 32-bit (#xx:32) immediate data as an operand.

The ADDS, SUBS, INC, and DEC instructions contain immediate data implicitly. Some bit manipulation instructions contain 3-bit immediate data in the instruction code, specifying a bit number. The TRAPA instruction contains 2-bit immediate data in its instruction code, specifying a vector address.

- (7) **Program-Counter Relative**—@(**d:8, PC**) or @(**d:16, PC**): This mode is used in the Bcc and BSR instructions. An 8-bit or 16-bit displacement contained in the instruction is sign-extended and added to the 24-bit PC contents to generate a branch address. Only the lower 24 bits of this branch address are valid; the upper 8 bits are all assumed to be 0 (H'00). The PC value to which the displacement is added is the address of the first byte of the next instruction, so the possible branching range is –126 to +128 bytes (–63 to +64 words) or –32766 to +32768 bytes (–16383 to +16384 words) from the branch instruction. The resulting value should be an even number.
- (8) Memory Indirect—@@aa:8: This mode can be used by the JMP and JSR instructions. The instruction code contains an 8-bit absolute address specifying a memory operand. This memory operand contains a branch address. The upper bits of the absolute address are all assumed to be 0, so the address range is 0 to 255 (H'000000 to H'0000FF).

Note that the first part of the address range is also the exception vector area. For further details, refer to section 4, Exception Handling.

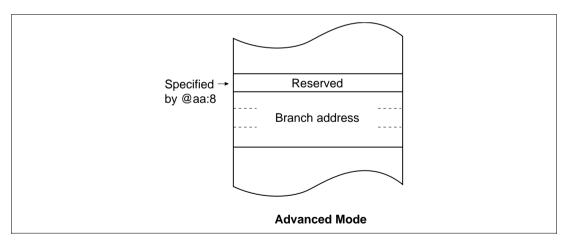


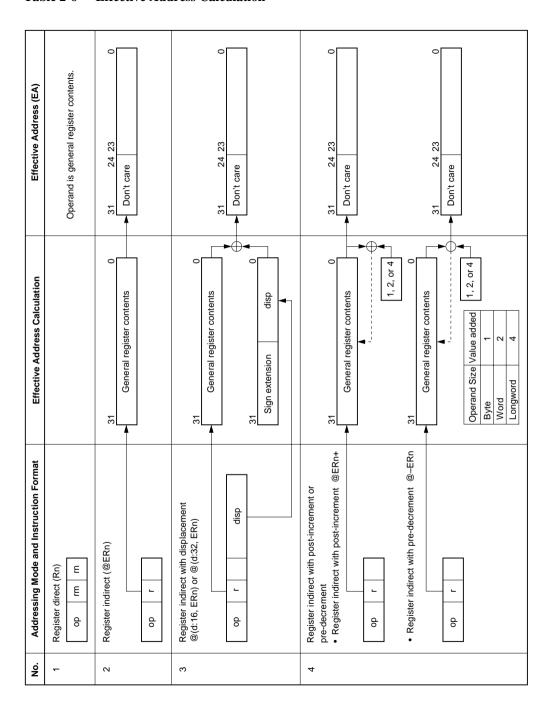
Figure 2-10 Branch Address Specification in Memory Indirect Mode

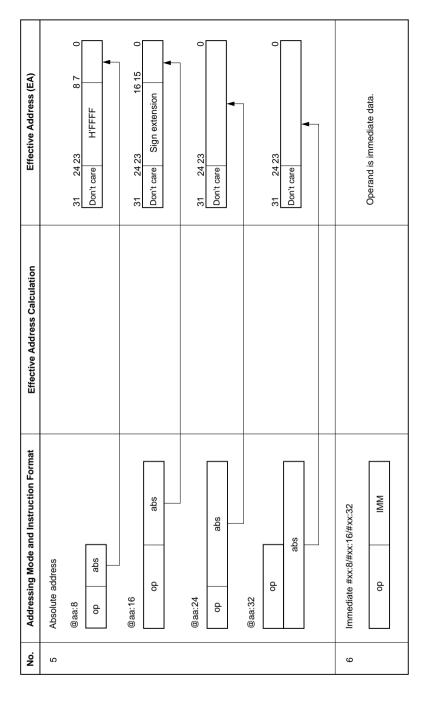
If an odd address is specified in word or longword memory access, or as a branch address, the least significant bit is regarded as 0, causing data to be accessed or instruction code to be fetched at the address preceding the specified address. (For further information, see section 2.5.2, Memory Data Formats.)

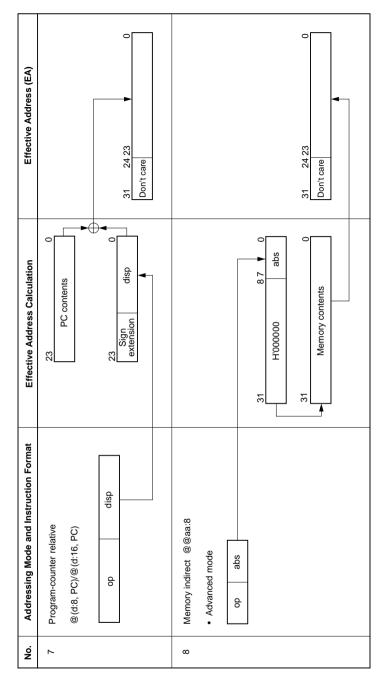
2.7.2 Effective Address Calculation

Table 2-6 indicates how effective addresses are calculated in each addressing mode.

Table 2-6 Effective Address Calculation







2.8 Processing States

2.8.1 Overview

The CPU has five main processing states: the reset state, exception handling state, program execution state, bus-released state, and power-down state. Figure 2-11 shows a diagram of the processing states. Figure 2-12 indicates the state transitions.

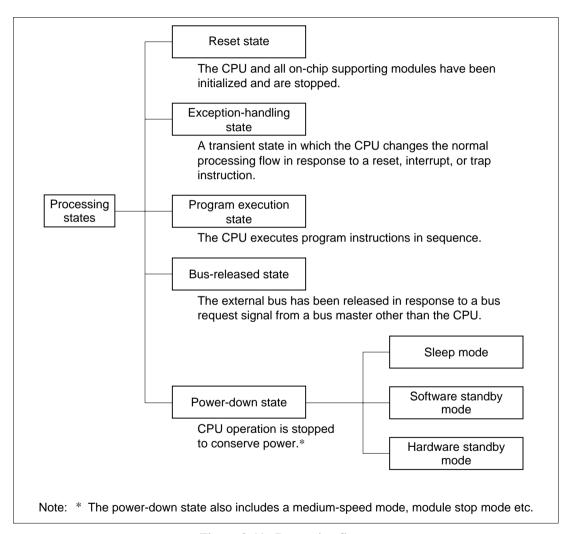


Figure 2-11 Processing States

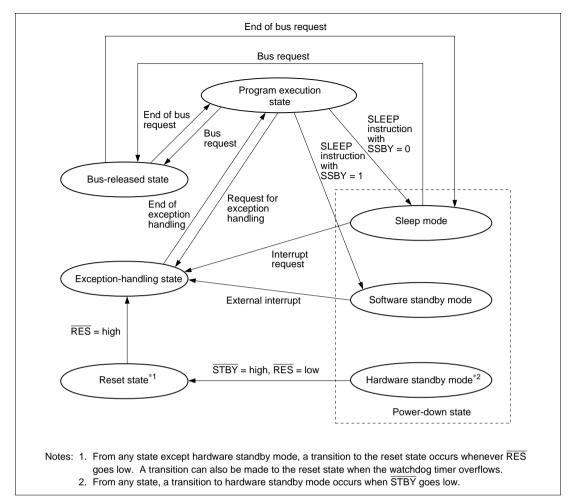


Figure 2-12 State Transitions

2.8.2 Reset State

When the \overline{RES} input goes low all current processing stops and the CPU enters the reset state. The CPU enters the power-on reset state when the NMI pin is high, or the manual reset* state when the NMI pin is low. All interrupts are masked in the reset state. Reset exception handling starts when the \overline{RES} signal changes from low to high.

The reset state can also be entered by a watchdog timer overflow. For details, refer to section 13, Watchdog Timer.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

2.8.3 Exception-Handling State

The exception-handling state is a transient state that occurs when the CPU alters the normal processing flow due to a reset, interrupt, or trap instruction. The CPU fetches a start address (vector) from the exception vector table and branches to that address.

(1) Types of Exception Handling and Their Priority

Exception handling is performed for traces, resets, interrupts, and trap instructions. Table 2-7 indicates the types of exception handling and their priority. Trap instruction exception handling is always accepted, in the program execution state.

Exception handling and the stack structure depend on the interrupt control mode set in SYSCR.

Table 2-7 Exception Handling Types and Priority

Priority	Type of Exception	Detection Timing	Start of Exception Handling		
High	Reset	Synchronized with clock	Exception handling starts immediately after a low-to-high transition at the RES pin, or when the watchdog timer overflows.		
	Trace	End of instruction execution or end of exception-handling sequence*1	When the trace (T) bit is set to 1, the trace starts at the end of the current instruction or current exception-handling sequence		
	Interrupt	End of instruction execution or end of exception-handling sequence* ²	When an interrupt is requested, exception handling starts at the end of the current instruction or current exception-handling sequence		
Low	Trap instruction	When TRAPA instruction is executed	Exception handling starts when a trap (TRAPA) instruction is executed*3		

Notes: 1. Traces are enabled only in interrupt control mode 2. Trace exception-handling is not executed at the end of the RTE instruction.

- 2. Interrupts are not detected at the end of the ANDC, ORC, XORC, and LDC instructions, or immediately after reset exception handling.
- 3. Trap instruction exception handling is always accepted, in the program execution state.

(2) Reset Exception Handling

After the \overline{RES} pin has gone low and the reset state has been entered, when \overline{RES} goes high again, reset exception handling starts. The CPU enters the power-on reset state when the NMI pin is high, or the manual reset* state when the NMI pin is low. When reset exception handling starts the CPU fetches a start address (vector) from the exception vector table and starts program execution from that address. All interrupts, including NMI, are disabled during reset exception handling and after it ends.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

(3) Traces

Traces are enabled only in interrupt control mode 2. Trace mode is entered when the T bit of EXR is set to 1. When trace mode is established, trace exception handling starts at the end of each instruction.

At the end of a trace exception-handling sequence, the T bit of EXR is cleared to 0 and trace mode is cleared. Interrupt masks are not affected.

The T bit saved on the stack retains its value of 1, and when the RTE instruction is executed to return from the trace exception-handling routine, trace mode is entered again. Trace exception-handling is not executed at the end of the RTE instruction.

Trace mode is not entered in interrupt control mode 0, regardless of the state of the T bit.

(4) Interrupt Exception Handling and Trap Instruction Exception Handling

When interrupt or trap-instruction exception handling begins, the CPU references the stack pointer (ER7) and pushes the program counter and other control registers onto the stack. Next, the CPU alters the settings of the interrupt mask bits in the control registers. Then the CPU fetches a start address (vector) from the exception vector table and program execution starts from that start address.

Figure 2-13 shows the stack after exception handling ends.

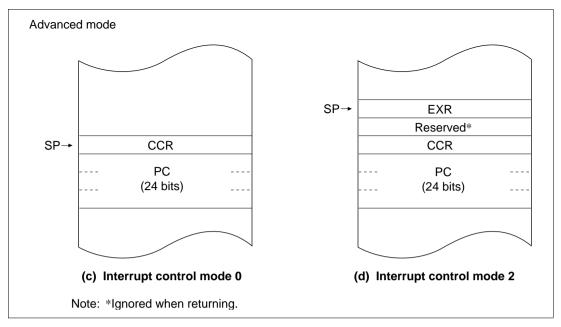


Figure 2-13 Stack Structure after Exception Handling (Examples)

2.8.4 Program Execution State

In this state the CPU executes program instructions in sequence.

2.8.5 Bus-Released State

This is a state in which the bus has been released in response to a bus request from a bus master other than the CPU. While the bus is released, the CPU halts.

There is one other bus master in addition to the CPU: the data transfer controller (DTC).

For further details, refer to section 6, Bus Controller.

2.8.6 Power-Down State

The power-down state includes both modes in which the CPU stops operating and modes in which the CPU does not stop. There are three modes in which the CPU stops operating: sleep mode, software standby mode, and hardware standby mode. There are also two other power-down modes: medium-speed mode, and module stop mode. In medium-speed mode the CPU and other bus masters operate on a medium-speed clock. Module stop mode permits halting of the operation of individual modules, other than the CPU. For details, refer to section 21, Power-Down State.

- (1) **Sleep Mode:** A transition to sleep mode is made if the SLEEP instruction is executed while the software standby bit (SSBY) in the standby control register (SBYCR) is cleared to 0. In sleep mode, CPU operations stop immediately after execution of the SLEEP instruction. The contents of CPU registers are retained.
- (2) **Software Standby Mode:** A transition to software standby mode is made if the SLEEP instruction is executed while the SSBY bit in SBYCR is set to 1. In software standby mode, the CPU and clock halt and all MCU operations stop. As long as a specified voltage is supplied, the contents of CPU registers and on-chip RAM are retained. The I/O ports also remain in their existing states.
- (3) **Hardware Standby Mode:** A transition to hardware standby mode is made when the STBY pin goes low. In hardware standby mode, the CPU and clock halt and all MCU operations stop. The on-chip supporting modules are reset, but as long as a specified voltage is supplied, on-chip RAM contents are retained.

2.9 Basic Timing

2.9.1 Overview

The CPU is driven by a system clock, denoted by the symbol ø. The period from one rising edge of ø to the next is referred to as a "state." The memory cycle or bus cycle consists of one, two, or three states. Different methods are used to access on-chip memory, on-chip supporting modules, and the external address space.

2.9.2 On-Chip Memory (ROM, RAM)

On-chip memory is accessed in one state. The data bus is 16 bits wide, permitting both byte and word transfer instruction. Figure 2-14 shows the on-chip memory access cycle. Figure 2-15 shows the pin states.

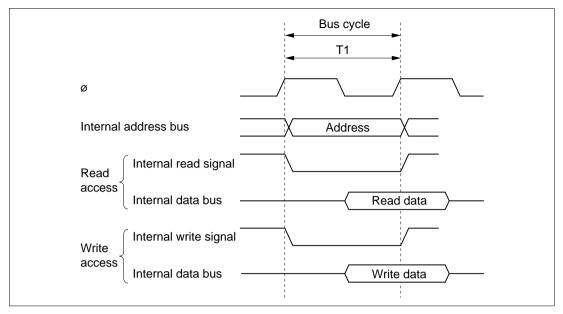


Figure 2-14 On-Chip Memory Access Cycle

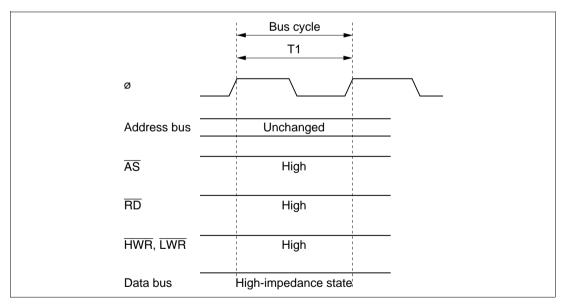


Figure 2-15 Pin States during On-Chip Memory Access

2.9.3 On-Chip Supporting Module Access Timing

The on-chip supporting modules are accessed in two states. The data bus is either 8 bits or 16 bits wide, depending on the particular internal I/O register being accessed. Figure 2-16 shows the access timing for the on-chip supporting modules. Figure 2-17 shows the pin states.

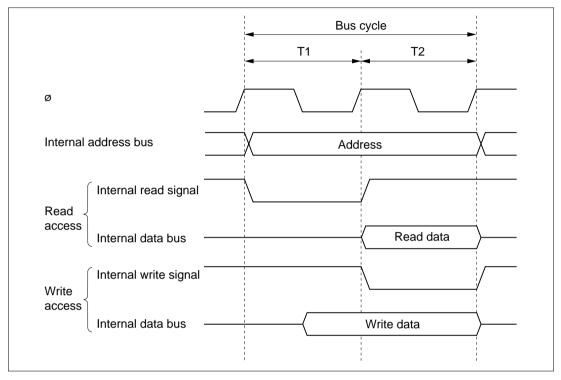


Figure 2-16 On-Chip Supporting Module Access Cycle

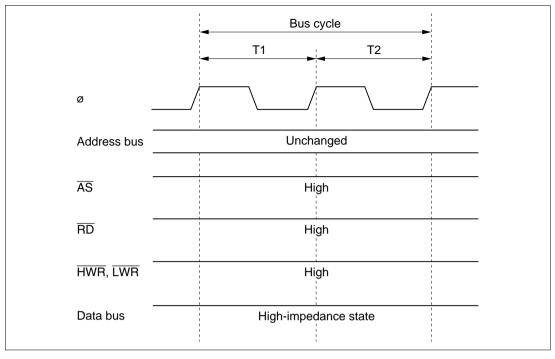


Figure 2-17 Pin States during On-Chip Supporting Module Access

2.9.4 External Address Space Access Timing

The external address space is accessed with an 8-bit or 16-bit data bus width in a two-state or three-state bus cycle. In three-state access, wait states can be inserted. For further details, refer to section 6, Bus Controller.

2.10 Usage Note

2.10.1 TAS Instruction

Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction. The TAS instruction is not generated by the Hitachi H8S and H8/300 series C/C++ compilers. If the TAS instruction is used as a user-defined intrinsic function, ensure that only register ER0, ER1, ER4, or ER5 is used.

Section 3 MCU Operating Modes

3.1 Overview

3.1.1 Operating Mode Selection (H8S/2357F-ZTATTM Only)

The H8S/2357F-ZTATTM has eight operating modes (modes 4 to 7, 10, 11, 14 and 15). These modes are determined by the mode pin (MD₂ to MD₀) and flash write enable pin (FWE) settings. The CPU operating mode and initial bus width can be selected as shown in table 3-1.

Table 3-1 lists the MCU operating modes.

Table 3-1 MCU Operating Mode Selection (H8S/2357F-ZTATTM Only)

MCU					CPU				al Data us
Operating Mode		MD_2	MD ₁	MD_0	Operating Mode	Description	On-Chip ROM	Initial Width	Max. Width
0	0	0	0	0	_	_	_	_	_
1	_			1	_				
2	_		1	0	_				
3	_			1					
4		1	0	0	Advanced	On-chip ROM disabled,	Disabled	16 bits	16 bits
5				1	_	expanded mode		8 bits	16 bits
6			1	0		On-chip ROM enabled, expanded mode	Enabled	8 bits	16 bits
7	-			1	-	Single-chip mode	-	_	_
8	1	0	0	0	_	_	_	_	_
9	-			1	-				
10	-		1	0	Advanced	Boot mode	Enabled	8 bits	16 bits
11	-			1				_	_
12	-	1	0	0	_	_	_	_	_
13	-			1	-				
14	=		1	0	Advanced	User program mode	Enabled	8 bits	16 bits
15	-			1	-			_	_

The CPU's architecture allows for 4 Gbytes of address space, but the H8S/2357 Series actually accesses a maximum of 16 Mbytes.

Modes 4 to 6 are externally expanded modes that allow access to external memory and peripheral devices.

The external expansion modes allow switching between 8-bit and 16-bit bus modes. After program execution starts, an 8-bit or 16-bit address space can be set for each area, depending on the bus controller setting. If 16-bit access is selected for any one area, 16-bit bus mode is set; if 8-bit access is selected for all areas, 8-bit bus mode is set.

Note that the functions of each pin depend on the operating mode.

Modes 10, 11, 14, and 15 are boot modes and user program modes in which the flash memory can be programmed and erased. For details, see section 19, ROM.

The H8S/2357F-ZTAT can only be used in modes 4 to 7, 10, 11, 14, and 15. This means that the flash write enable pin and mode pins must be set to select one of these modes.

Do not change the inputs at the mode pins during operation.

3.1.2 Operating Mode Selection (Z-TAT, Mask ROM, ROMless Version, H8S/2398F-ZTAT, H8S/2396F-ZTAT, and H8S/2395F-ZTAT)

The H8S/2357 Series has four operating modes (modes 4 to 7). These modes enable selection of the CPU operating mode, enabling/disabling of on-chip ROM, and the initial bus width setting, by setting the mode pins (MD₂ to MD₀).

Table 3-2 lists the MCU operating modes.

Table 3-2 MCU Operating Mode Selection (ZTAT, Mask ROM, and ROMless, H8S/2398F-ZTAT, H8S/2396F-ZTAT, H8S/2395F-ZTAT Versions)

MCU				CPU			Extern	al Data Bus
Operating Mode	MD_2	MD ₁	MD_0	Operating Mode	Description	On-Chip ROM	Initial Width	Max. Width
0	0	0	0	_	_	_	_	_
1			1					
2*1	_	1	0	_				
3* ¹	_		1	_				
4*2	1	0	0	Advanced	On-chip ROM disabled,	Disabled	16 bits	16 bits
5*2	_		1	_	expanded mode		8 bits	16 bits
6	_	1	0	_	On-chip ROM enabled, expanded mode	Enabled	8 bits	16 bits
7	_		1	_	Single-chip mode	=	_	_

Notes: 1. In the H8S/2395 F-ZTAT, H8S/2396 F-ZTAT, and H8S/2398 F-ZTAT versions, modes 2 and 3 indicate boot mode. For details on boot mode of the H8S/2395 F-ZTAT and H8S/2396 F-ZTAT versions, refer to table 19-56 in section 19.26, On-Board Programming Modes. For details on boot mode of the H8S/2398 F-ZTAT version, refer to table 19-35 in section 19.17, On-Board Programming Modes.

In addition, for details on user program mode of said products, refer also to tables 19-56 and 19-35 in sections 19.26 and 19.17, On-Board Programming Modes.

2. In ROMless version, only modes 4 and 5 are available.

The CPU's architecture allows for 4 Gbytes of address space, but the H8S/2357 Series actually accesses a maximum of 16 Mbytes.

Modes 4 to 6 are externally expanded modes that allow access to external memory and peripheral devices.

The external expansion modes allow switching between 8-bit and 16-bit bus modes. After program execution starts, an 8-bit or 16-bit address space can be set for each area, depending on the bus controller setting. If 16-bit access is selected for any one area, 16-bit bus mode is set; if 8-bit access is selected for all areas, 8-bit bus mode is set.

Note that the functions of each pin depend on the operating mode.

The H8S/2357 Series cannot be used in modes 4 to 7. This means that the mode pins must be set to select 4 to 7 modes.

Do not change the inputs at the mode pins during operation.

3.1.3 Register Configuration

The H8S/2357 Series has a mode control register (MDCR) that indicates the inputs at the mode pins (MD $_2$ to MD $_0$), and a system control register (SYSCR) and a system control register 2 (SYSCR2)*2 that control the operation of the H8S/2357 Series. Table 3-3 summarizes these registers.

Table 3-3 MCU Registers

Name	Abbreviation	R/W	Initial Value	Address*1
Mode control register	MDCR	R	Undetermined	H'FF3B
System control register	SYSCR	R/W	H'01	H'FF39
System control register 2*2	SYSCR2	R/W	H'00	H'FF42

Notes: 1. Lower 16 bits of the address.

The SYSCR2 register can only be used in the F-ZTAT version. In the mask ROM and ZTAT versions, this register cannot be written to and will return an undefined value if read.

3.2 Register Descriptions

3.2.1 Mode Control Register (MDCR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	_	MDS2	MDS1	MDS0
Initial va	lue :	1	0	0	0	0	*	*	*
R/W	:	_	_	_	_	_	R	R	R

Note: * Determined by pins MD₂ to MD₀.

MDCR is an 8-bit read-only register that indicates the current operating mode of the H8S/2357 Series.

Bit 7—Reserved: This bit cannot be modified and is always read as 1.

Bits 6 to 3—Reserved: These bits cannot be modified and are always read as 0.

Bits 2 to 0—Mode Select 2 to 0 (MDS2 to MDS0): These bits indicate the input levels at pins MD_2 to MD_0 (the current operating mode). Bits MDS2 to MDS0 correspond to MD_2 to MD_0 . MDS2 to MDS0 are read-only bits, they cannot be written to. The mode pin $(MD_2$ to MD_0) input levels are latched into these bits when MDCR is read. These latches are canceled by a power-on reset, but are retained after a manual reset.*

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

3.2.2 System Control Register (SYSCR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	INTM1	INTM0	NMIEG	_	_	RAME
Initial va	alue :	0	0	0	0	0	0	0	1
R/W	:	R/W	_	R/W	R/W	R/W	*	R/W	R/W

Note: * R/W in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398.

Bit 7—Reserved: Only 0 should be written to this bit.

Bit 6—Reserved: This bit cannot be modified and is always read as 0.

Bits 5 and 4—Interrupt Control Mode 1 and 0 (INTM1, INTM0): These bits select the control mode of the interrupt controller. For details of the interrupt control modes, see section 5.4.1, Interrupt Control Modes and Interrupt Operation.

Bit 5 INTM1	Bit 4 INTM0	Interrupt Control Mode	Description			
0	0	0	Control of interrupts by I bit	(Initial value)		
	1	_	Setting prohibited			
1	0	2	Control of interrupts by I2 to I0 bits and IPR			
	1	_	Setting prohibited			

Bit 3—NMI Edge Select (NMIEG): Selects the valid edge of the NMI interrupt input.

Bit 3 NMIEG	Description	
0	An interrupt is requested at the falling edge of NMI input	(Initial value)
1	An interrupt is requested at the rising edge of NMI input	

Bit 2—Reserved: This bit cannot be modified and is always read as 0.

This bit is reserved in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398. Only 0 should be written to this bit.

Bit 1—Reserved: Only 0 should be written to this bit.

Bit 0—RAM Enable (RAME): Enables or disables the on-chip RAM. The RAME bit is initialized when the reset status is released. It is not initialized in software standby mode.

Bit 0 RAME	Description	
0	On-chip RAM is disabled	
1	On-chip RAM is enabled	(Initial value)

3.2.3 System Control Register 2 (SYSCR2) (F-ZTAT Only)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	FLSHE	_	_	_
Initial value	:	0	0	0	0	0	0	0	0
R/W	:	_	_	_	_	R/W	_	_	_

SYSCR2 is an 8-bit readable/writable register that performs on-chip flash memory control.

SYSCR2 is initialized to H'00 by a reset and in hardware standby mode.

SYSCR2 can only be accessed in the F-ZTAT version. In other versions, this register cannot be written to and will return an undefined value if read.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—Flash Memory Control Register Enable (FLSHE): Controls CPU access to the flash memory control registers (FLMCR1, FLMCR2, EBR1, and EBR2). For details, see section 19, ROM.

Bit 3 FLSHE	Description
0	Flash control registers are not selected for addresses H'FFFFC8 to H'FFFFCB
	(Initial value)
1	Flash control registers are selected for addresses H'FFFFC8 to H'FFFFCB

Bits 2 to 0—Reserved: These bits cannot be modified and are always read as 0.

3.3 Operating Mode Descriptions

3.3.1 Modes 1

Mode 1 is not supported in this LSI, and must not be set.

3.3.2 Mode 2 (H8S/2398F-ZTAT, H8S/2396F-ZTAT, H8S/2395F-ZTAT Only)

Mode 2 in the H8S/2398 F-ZTAT, H8S/2396 F-ZTAT, and H8S/2395 F-ZTAT versions indicates flash-memory boot mode. For details, refer to section 19, ROM. The operation of the MCU is the same as that in mode 6.

3.3.3 Mode 3 (H8S/2398F-ZTAT, H8S/2396F-ZTAT, H8S/2395F-ZTAT Only)

Mode 3 in the H8S/2398 F-ZTAT, H8S/2396 F-ZTAT, and H8S/2395 F-ZTAT versions indicates flash-memory boot mode. For details, refer to section 19, ROM. The operation of the MCU is the same as that in mode 7.

3.3.4 Mode 4 (On-chip ROM Disabled Expansion Mode)

The CPU can access a 16-Mbyte address space in advanced mode. The on-chip ROM is disabled.

Ports A, B and C function as an address bus, ports D and E function as a data bus, and part of port F carries bus control signals.

The initial bus mode after a reset is 16 bits, with 16-bit access to all areas. However, note that if 8-bit access is designated by the bus controller for all areas, the bus mode switches to 8 bits.

3.3.5 Mode 5 (On-chip ROM Disabled Expansion Mode)

The CPU can access a 16-Mbyte address space in advanced mode. The on-chip ROM is disabled.

Ports A, B and C function as an address bus, ports D and E function as a data bus, and part of port F carries bus control signals.

The initial bus mode after a reset is 8 bits, with 8-bit access to all areas. However, note that if at least one area is designated for 16-bit access by the bus controller, the bus mode switches to 16 bits and port E becomes a data bus.

3.3.6 Mode 6 (On-chip ROM Enabled Expansion Mode)

The CPU can access a 16-Mbyte address space in advanced mode. The on-chip ROM is enabled.

Ports A, B and C function as input ports immediately after a reset. They can each be set to output addresses by setting the corresponding bits in the data direction register (DDR) to 1. Port D functions as a data bus, and part of port F carries bus control signals.

The initial bus mode after a reset is 8 bits, with 8-bit access to all areas. However, note that if at least one area is designated for 16-bit access by the bus controller, the bus mode switches to 16 bits and port E becomes a data bus.

3.3.7 Mode 7 (Single-Chip Mode)

The CPU can access a 16-Mbyte address space in advanced mode. The on-chip ROM is enabled, but external addresses cannot be accessed.

All I/O ports are available for use as input-output ports.

3.3.8 Modes 8 and 9 (H8S/2357F-ZTAT Only)

Modes 8 and 9 are not supported in the H8S/2357 Series, and must not be set.

3.3.9 Mode 10 (H8S/2357F-ZTAT Only)

This is a flash memory boot mode. For details, see section 19, ROM.

MCU operation is the same as in mode 6.

3.3.10 Mode 11 (H8S/2357F-ZTAT Only)

This is a flash memory boot mode. For details, see section 19, ROM.

MCU operation is the same as in mode 7.

3.3.11 Modes 12 and 13 (H8S/2357F-ZTAT Only)

Modes 12 and 13 are not supported in the H8S/2357 Series, and must not be set.

3.3.12 Mode 14 (H8S/2357F-ZTAT Only)

This is a flash memory user program mode. For details, see section 19, ROM.

MCU operation is the same as in mode 6.

3.3.13 Mode 15 (H8S/2357F-ZTAT Only)

This is a flash memory user program mode. For details, see section 19, ROM.

MCU operation is the same as in mode 7.

3.4 Pin Functions in Each Operating Mode

The pin functions of ports A to F vary depending on the operating mode. Table 3-4 shows their functions in each operating mode.

Table 3-4 Pin Functions in Each Mode

Port		Mode 2* ⁴	Mode 3* ⁴	Mode 4* ²	Mode 5* ²	Mode 6	Mode 7	Mode 10* ³	Mode 11* ³	Mode 14* ³	Mode 15* ³
Port A	PA ₇ to PA ₅	P*1/A	Р	P*1/A	P*1/A	P*1/A	Р	P*1/A	Р	P*1/A	Р
	PA ₄ to PA ₀	=		A	Α	_					
Port B		P*1/A	Р	Α	Α	P*1/A	Р	P*1/A	Р	P*1/A	Р
Port C	;	P*1/A	Р	Α	Α	P*1/A	Р	P*1/A	Р	P*1/A	Р
Port D)	D	Р	D	D	D	Р	D	Р	D	Р
Port E		P*1/D	Р	P/D*1	P*1/D	P*1/D	Р	P*1/D	Р	P*1/D	Р
Port F	PF ₇	P/C*1	P/C*1	P/C*1	P/C*1	P/C*1	P*1/C	P/C*1	P*1/C	P/C*1	P*1/C
	PF ₆ to PF ₃	С	С	С	С	С	Р	С	Р	С	Р
	PF ₂ to PF ₀	P*1/C	P*1/C	P*1/C	P*1/C	P*1/C	_	P*1/C	_	P*1/C	

Legend

P: I/O port

A: Address bus output

D: Data bus I/O

C: Control signals, clock I/O

Notes: 1. After reset

- 2. In ROMless version, only modes 4 and 5 are available.
- 3. Applies to the H8S/2357F-ZTAT version only.
- 4. Applies to the H8S/2398F-ZTAT, H8S/2396F-ZTAT, H8S/2395F-ZTAT version only.

3.5 Memory Map in Each Operating Mode

Figure 3-1 to 3-4 show memory maps for each of the operating modes.

The address space is 16 Mbytes in modes 4 to 7.

The address space is divided into eight areas for modes 4 to 7. For details, see section 6, Bus Controller.

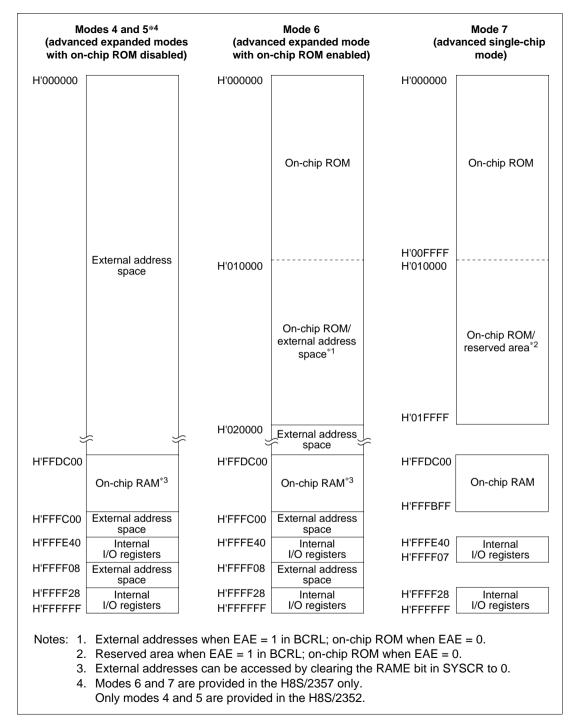
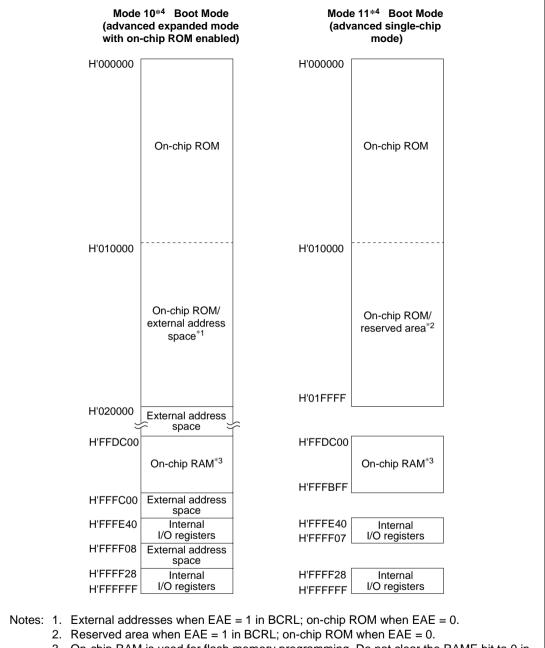
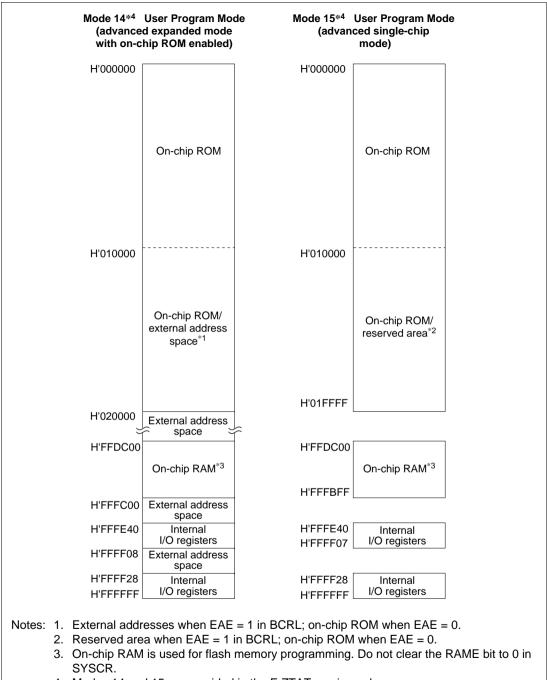


Figure 3-1 Memory Map in Each Operating Mode (H8S/2357, H8S/2352) (1)



- On-chip RAM is used for flash memory programming. Do not clear the RAME bit to 0 in SYSCR.
- 4. Modes 10 and 11 are provided in the F-ZTAT version only.

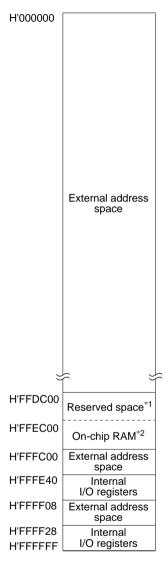
Figure 3-1 Memory Map in Each Operating Mode (H8S/2357, H8S/2352) (2)



4. Modes 14 and 15 are provided in the F-ZTAT version only.

Figure 3-1 Memory Map in Each Operating Mode (H8S/2357, H8S/2352) (3)

Modes 4 and 5 (advanced expanded modes with on-chip ROM disabled)



Notes: 1. This is a reserved space. Access to this space is inhibited. The space can be made available for use as an external address space by clearing the RAME bit of the SYSCR to 0.

2. External addresses can be accessed by clearing the RAME bit in SYSCR to 0.

Figure 3-2 Memory Map in Each Operating Mode (H8S/2390)

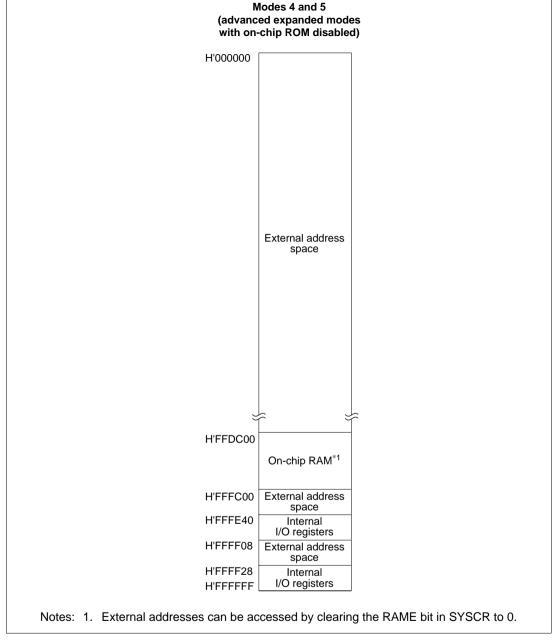


Figure 3-3 Memory Map in Each Operating Mode (H8S/2392)

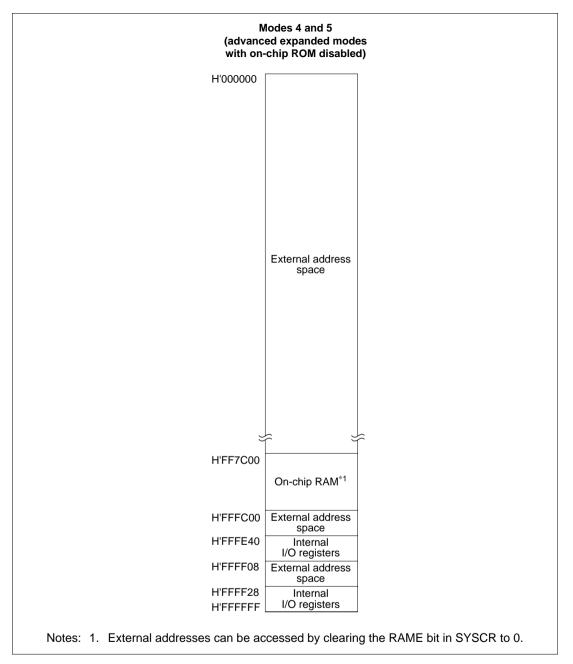


Figure 3-4 Memory Map in Each Operating Mode (H8S/2394)

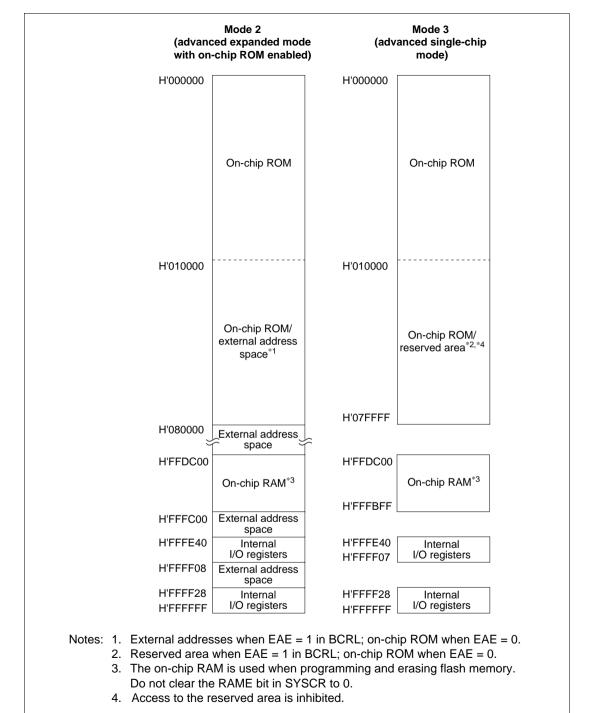


Figure 3-5 Memory Map in Each Operating Mode (H8S/2396) (1)

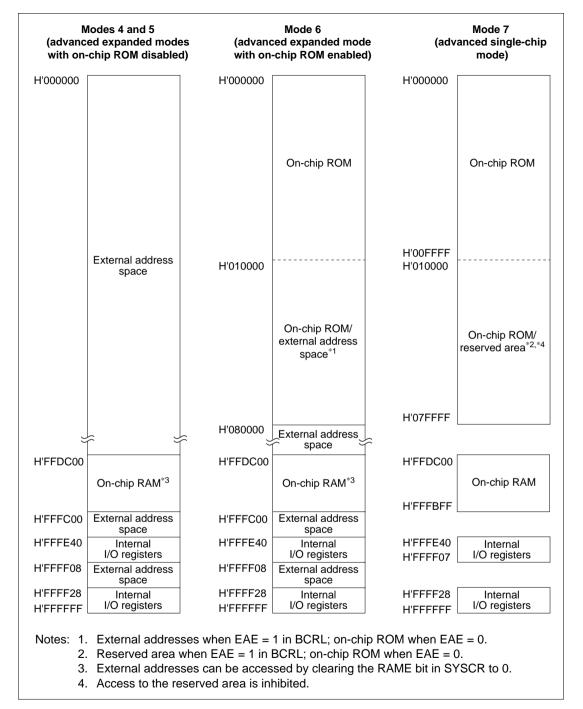


Figure 3-5 Memory Map in Each Operating Mode (H8S/2396) (2)

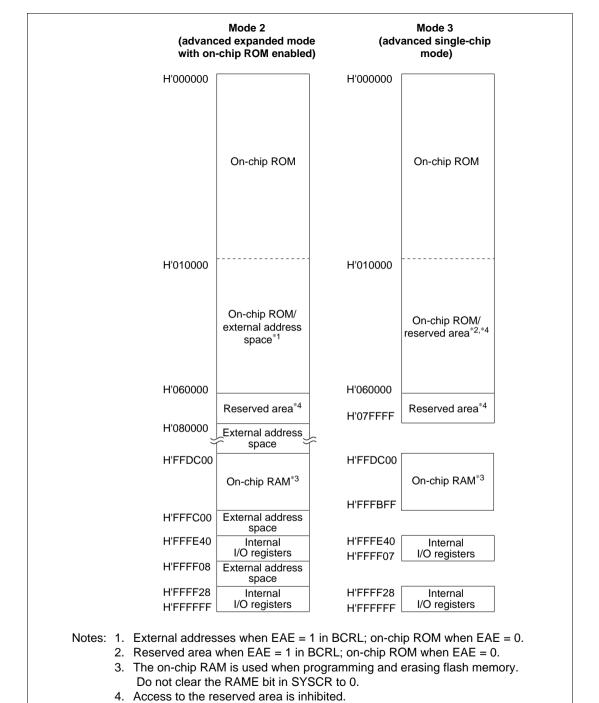


Figure 3-6 Memory Map in Each Operating Mode (H8S/2395) (1)

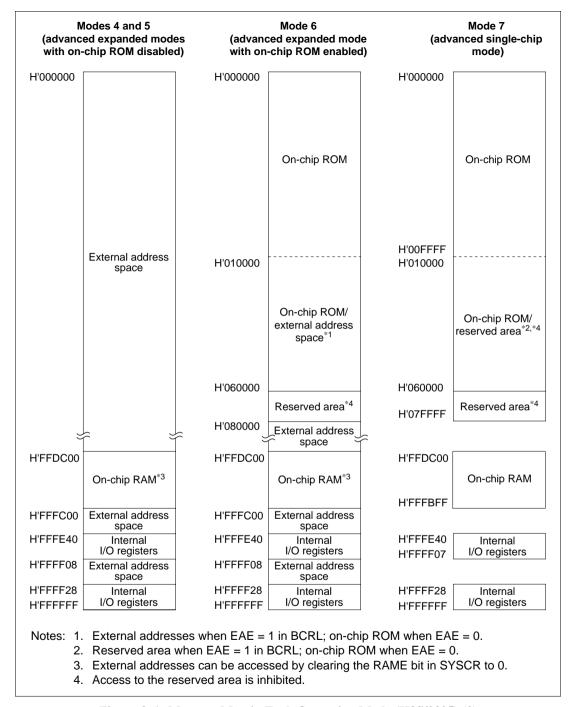
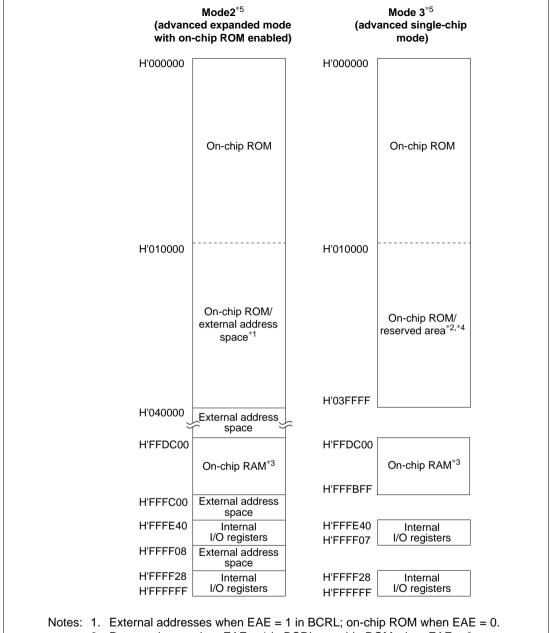


Figure 3-6 Memory Map in Each Operating Mode (H8S/2395) (2)



- 2. Reserved area when EAE = 1 in BCRL; on-chip ROM when EAE = 0.
- 3. The on-chip RAM is used when programming and erasing flash memory. Do not clear the RAME bit in SYSCR to 0.
- 4. Access to the reserved area is inhibited.
- 5. Modes 2 and 3 are provided in the F-ZTAT version only.

Figure 3-7 Memory Map in Each Operating Mode (H8S/2398) (1)

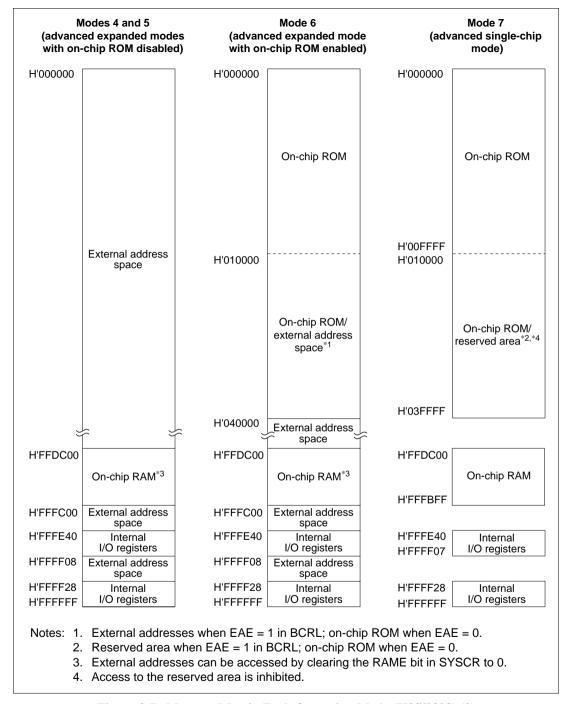


Figure 3-7 Memory Map in Each Operating Mode (H8S/2398) (2)

Section 4 Exception Handling

4.1 Overview

4.1.1 **Exception Handling Types and Priority**

As table 4-1 indicates, exception handling may be caused by a reset, trap instruction, or interrupt. Exception handling is prioritized as shown in table 4-1. If two or more exceptions occur simultaneously, they are accepted and processed in order of priority. Trap instruction exceptions are accepted at all times, in the program execution state.

Exception handling sources, the stack structure, and the operation of the CPU vary depending on the interrupt control mode set by the INTM0 and INTM1 bits of SYSCR.

Table 4-1 **Exception Types and Priority**

Priority	Exception Type	Start of Exception Handling				
High	Reset	Starts immediately after a low-to-high transition at the RES pin, or when the watchdog timer overflows. The CPU enters the power-on reset state when the NMI pin is high, or the manual reset* state when the NMI pin is low.				
	Trace*1	Starts when execution of the current instruction or exception handling ends, if the trace (T) bit is set to 1				
	Interrupt	Starts when execution of the current instruction or exception handling ends, if an interrupt request has been issued*2				
Low	Trap instruction (TRAPA)*3 Started by execution of a trap instruction (TRAPA)					

- Notes: 1. Traces are enabled only in interrupt control mode 2. Trace exception handling is not executed after execution of an RTE instruction.
 - 2. Interrupt detection is not performed on completion of ANDC, ORC, XORC, or LDC instruction execution, or on completion of reset exception handling.
 - 3. Trap instruction exception handling requests are accepted at all times in program execution state.
 - 4. Manual reset is only supported in the H8S/2357 ZTAT version.

4.1.2 Exception Handling Operation

Exceptions originate from various sources. Trap instructions and interrupts are handled as follows:

- 1. The program counter (PC), condition code register (CCR), and extended register (EXR) are pushed onto the stack.
- 2. The interrupt mask bits are updated. The T bit is cleared to 0.
- 3. A vector address corresponding to the exception source is generated, and program execution starts from that address.

For a reset exception, steps 2 and 3 above are carried out.

4.1.3 Exception Vector Table

The exception sources are classified as shown in figure 4-1. Different vector addresses are assigned to different exception sources.

Table 4-2 lists the exception sources and their vector addresses.

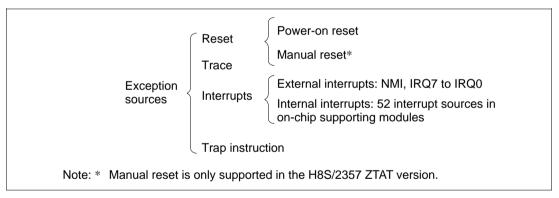


Figure 4-1 Exception Sources

In modes 6 and 7 the on-chip ROM available for use after a power-on reset is the 64-kbyte area comprising addresses H'000000 to H'00FFFF. Care is required when setting vector addresses. In this case, clearing the EAE bit in BCRL enables the 128-kbyte (256 kbytes/384 kbytes/512 kbytes)* area comprising address H'000000 to H'01FFF (H'03FFFF/H'05FFFF/H'07FFFF)* to be used.

Note: * Since these values are different according to the on-chip ROM capacitance, see section 3.5, Memory Map in Each Operating Mode.

Table 4-2 Exception Vector Table

			Vector Address*1
Exception Source		Vector Number	Advanced Mode
Power-on reset		0	H'0000 to H'0003
Manual reset*3		1	H'0004 to H'0007
Reserved for syster	m use	2	H'0008 to H'000B
		3	H'000C to H'000F
		4	H'0010 to H'0013
Trace		5	H'0014 to H'0017
Reserved for system	m use	6	H'0018 to H'001B
External interrupt	NMI	7	H'001C to H'001F
Trap instruction (4 s	sources)	8	H'0020 to H'0023
		9	H'0024 to H'0027
		10	H'0028 to H'002B
		11	H'002C to H'002F
Reserved for syster	m use	12	H'0030 to H'0033
		13	H'0034 to H'0037
		14	H'0038 to H'003B
		15	H'003C to H'003F
External interrupt	IRQ0	16	H'0040 to H'0043
	IRQ1	17	H'0044 to H'0047
	IRQ2	18	H'0048 to H'004B
	IRQ3	19	H'004C to H'004F
	IRQ4	20	H'0050 to H'0053
	IRQ5	21	H'0054 to H'0057
	IRQ6	22	H'0058 to H'005B
	IRQ7	23	H'005C to H'005F
Internal interrupt*2		24 	H'0060 to H'0063
		91	H'016C to H'016F

Notes: 1. Lower 16 bits of the address.

- 2. For details of internal interrupt vectors, see section 5.3.3, Interrupt Exception Handling Vector Table.
- 3. Manual reset is only supported in the H8S/2357 ZTAT version.

4.2 Reset

4.2.1 Overview

A reset has the highest exception priority.

When the \overline{RES} pin goes low, all processing halts and the H8S/2357 Series enters the reset state. A reset initializes the internal state of the CPU and the registers of on-chip supporting modules. Immediately after a reset, interrupt control mode 0 is set.

Reset exception handling begins when the \overline{RES} pin changes from low to high.

In the F-ZTAT, mask ROM, and ROMless versions, a reset is always a power-on reset, regardless of the NMI pin level at the time. Also, a reset caused by the watchdog timer is always a power-on reset, regardless of the setting of the RSTS bit in the RSTCR register.

In the ZTAT version, a reset may be either a power-on reset or a manual reset, according to the NMI pin level at the time. A reset caused by the watchdog timer, also, may be either a power-on reset or a manual reset*.

For details see section 13, Watchdog Timer.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

4.2.2 Reset Types

A reset can be of either of two types: a power-on reset or a manual reset*. Reset types are shown in table 4-3. A power-on reset should be used when powering on.

The internal state of the CPU is initialized by either type of reset. A power-on reset also initializes all the registers in the on-chip supporting modules, while a manual reset* initializes all the registers in the on-chip supporting modules except for the bus controller and I/O ports, which retain their previous states.

With a manual reset*, since the on-chip supporting modules are initialized, ports used as on-chip supporting module I/O pins are switched to I/O ports controlled by DDR and DR.

Table 4-3 Reset Types

Reset Transition

	Co	nditions		Internal State
Туре	NMI	RES	CPU	On-Chip Supporting Modules
Power-on reset	High	Low	Initialized	Initialized
Manual reset*	Low	Low	Initialized	Initialized, except for bus controller and I/O ports

A reset caused by the watchdog timer can also be of either of two types: a power-on reset or a manual reset*.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

4.2.3 Reset Sequence

The H8S/2357 Series enters the reset state when the \overline{RES} pin goes low.

To ensure that the H8S/2357 Series is reset, hold the \overline{RES} pin low for at least 20 ms at power-up. To reset the H8S/2357 Series during operation, hold the \overline{RES} pin low for at least 20 states.

When the \overline{RES} pin goes high after being held low for the necessary time, the H8S/2357 Series starts reset exception handling as follows:

- 1. The internal state of the CPU and the registers of the on-chip supporting modules are initialized, the T bit is cleared to 0 in EXR, and the I bit is set to 1 in EXR and CCR.
- 2. The reset exception handling vector address is read and transferred to the PC, and program execution starts from the address indicated by the PC.

Figure 4-2 show examples of the reset sequence.

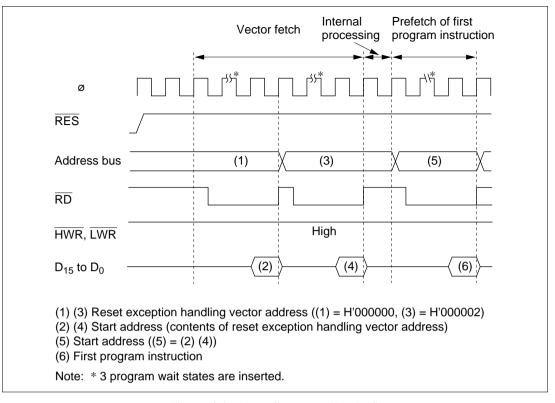


Figure 4-2 Reset Sequence (Mode 4)

4.2.4 Interrupts after Reset

If an interrupt is accepted after a reset but before the stack pointer (SP) is initialized, the PC and CCR will not be saved correctly, leading to a program crash. To prevent this, all interrupt requests, including NMI, are disabled immediately after a reset. Since the first instruction of a program is always executed immediately after the reset state ends, make sure that this instruction initializes the stack pointer (example: MOV.L #xx:32, SP).

4.2.5 State of On-Chip Supporting Modules after Reset Release

After reset release, MSTPCR is initialized to H'3FFF and all modules except the DMAC and DTC enter module stop mode. Consequently, on-chip supporting module registers cannot be read or written to. Register reading and writing is enabled when module stop mode is exited.

4.3 Traces

Traces are enabled in interrupt control mode 2. Trace mode is not activated in interrupt control mode 0, irrespective of the state of the T bit. For details of interrupt control modes, see section 5, Interrupt Controller.

If the T bit in EXR is set to 1, trace mode is activated. In trace mode, a trace exception occurs on completion of each instruction.

Trace mode is canceled by clearing the T bit in EXR to 0. It is not affected by interrupt masking.

Table 4-4 shows the state of CCR and EXR after execution of trace exception handling.

Interrupts are accepted even within the trace exception handling routine.

The T bit saved on the stack retains its value of 1, and when control is returned from the trace exception handling routine by the RTE instruction, trace mode resumes.

Trace exception handling is not carried out after execution of the RTE instruction.

Table 4-4 Status of CCR and EXR after Trace Exception Handling

		CCR		EXR		
Interrupt Control Mode	Ī	UI	l2 to l0	Т		
0		Trace exception	on handling cannot b	oe used.		
2	1	_	_	0		

Legend

1: Set to 1

0: Cleared to 0

—: Retains value prior to execution.

4.4 Interrupts

Interrupt exception handling can be requested by nine external sources (NMI, IRQ7 to IRQ0) and 52 internal sources in the on-chip supporting modules. Figure 4-3 classifies the interrupt sources and the number of interrupts of each type.

The on-chip supporting modules that can request interrupts include the watchdog timer (WDT), refresh timer, 16-bit timer-pulse unit (TPU), 8-bit timer, serial communication interface (SCI), data transfer controller (DTC), DMA controller (DMAC), and A/D converter. Each interrupt source has a separate vector address.

NMI is the highest-priority interrupt. Interrupts are controlled by the interrupt controller. The interrupt controller has two interrupt control modes and can assign interrupts other than NMI to eight priority/mask levels to enable multiplexed interrupt control.

For details of interrupts, see section 5, Interrupt Controller.

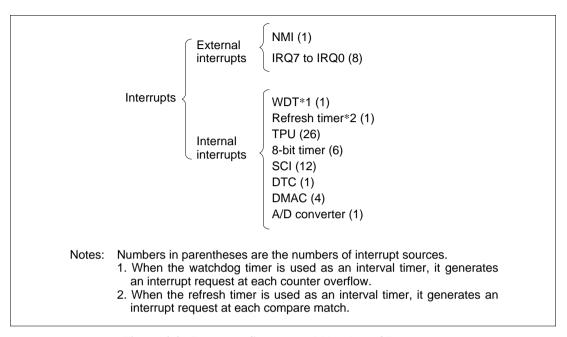


Figure 4-3 Interrupt Sources and Number of Interrupts

4.5 Trap Instruction

Trap instruction exception handling starts when a TRAPA instruction is executed. Trap instruction exception handling can be executed at all times in the program execution state.

The TRAPA instruction fetches a start address from a vector table entry corresponding to a vector number from 0 to 3, as specified in the instruction code.

Table 4-5 shows the status of CCR and EXR after execution of trap instruction exception handling.

Table 4-5 Status of CCR and EXR after Trap Instruction Exception Handling

		CCR	EXR		
Interrupt Control Mode	I	UI	l2 to l0	Т	
0	1	_	_	_	
2	1	_	_	0	

Legend

1: Set to 1

0: Cleared to 0

—: Retains value prior to execution.

4.6 Stack Status after Exception Handling

Figure 4-4 shows the stack after completion of trap instruction exception handling and interrupt exception handling.

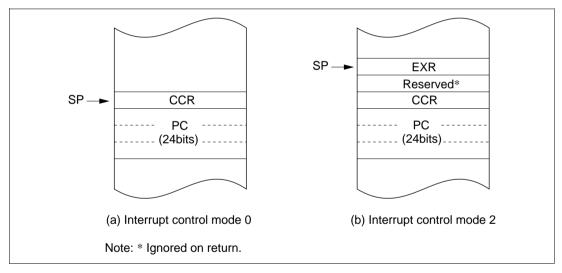


Figure 4-4 Stack Status after Exception Handling (Advanced Modes)

4.7 Notes on Use of the Stack

When accessing word data or longword data, the H8S/2357 Series assumes that the lowest address bit is 0. The stack should always be accessed by word transfer instruction or longword transfer instruction, and the value of the stack pointer (SP, ER7) should always be kept even. Use the following instructions to save registers:

```
PUSH.W Rn (or MOV.W Rn, @-SP)

PUSH.L ERn (or MOV.L ERn, @-SP)
```

Use the following instructions to restore registers:

```
POP.W Rn (or MOV.W @SP+, Rn)
POP.L ERn (or MOV.L @SP+, ERn)
```

Setting SP to an odd value may lead to a malfunction. Figure 4-5 shows an example of what happens when the SP value is odd.

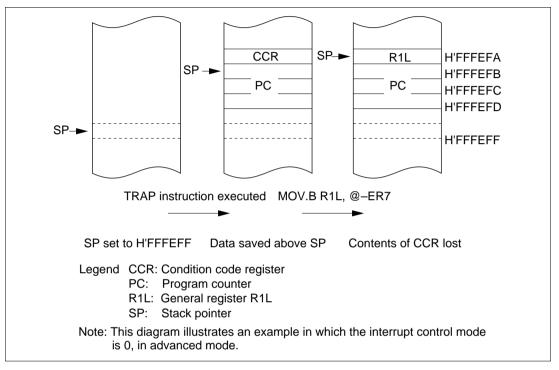


Figure 4-5 Operation when SP Value is Odd

Section 5 Interrupt Controller

5.1 Overview

5.1.1 Features

The H8S/2357 Series controls interrupts by means of an interrupt controller. The interrupt controller has the following features:

- Two interrupt control modes
 - Any of two interrupt control modes can be set by means of the INTM1 and INTM0 bits in the system control register (SYSCR).
- Priorities settable with IPR
 - An interrupt priority register (IPR) is provided for setting interrupt priorities. Eight priority levels can be set for each module for all interrupts except NMI.
 - NMI is assigned the highest priority level of 8, and can be accepted at all times.
- Independent vector addresses
 - All interrupt sources are assigned independent vector addresses, making it unnecessary for the source to be identified in the interrupt handling routine.
- Nine external interrupts
 - NMI is the highest-priority interrupt, and is accepted at all times. Rising edge or falling edge can be selected for NMI.
 - Falling edge, rising edge, or both edge detection, or level sensing, can be selected for IRQ7 to IRQ0.
- DTC and DMAC control
 - DTC and DMAC activation is performed by means of interrupts.

5.1.2 Block Diagram

A block diagram of the interrupt controller is shown in Figure 5-1.

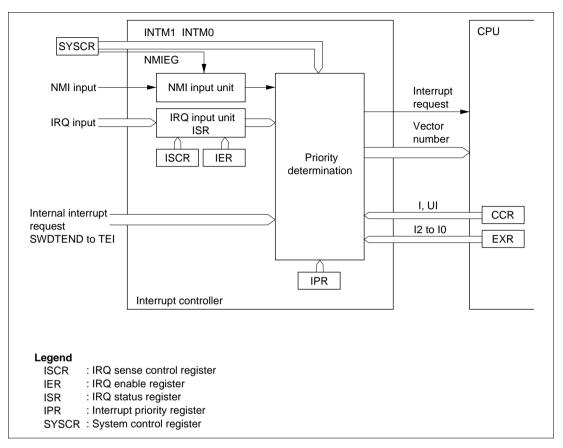


Figure 5-1 Block Diagram of Interrupt Controller

5.1.3 Pin Configuration

Table 5-1 summarizes the pins of the interrupt controller.

Table 5-1 Interrupt Controller Pins

Name	Symbol	I/O	Function
Nonmaskable interrupt	NMI	Input	Nonmaskable external interrupt; rising or falling edge can be selected
External interrupt requests 7 to 0	ĪRQ7 to ĪRQ0	Input	Maskable external interrupts; rising, falling, or both edges, or level sensing, can be selected

5.1.4 Register Configuration

Table 5-2 summarizes the registers of the interrupt controller.

Table 5-2 Interrupt Controller Registers

Name	Abbreviation	R/W	Initial Value	Address*1
System control register	SYSCR	R/W	H'01	H'FF39
IRQ sense control register H	ISCRH	R/W	H'00	H'FF2C
IRQ sense control register L	ISCRL	R/W	H'00	H'FF2D
IRQ enable register	IER	R/W	H'00	H'FF2E
IRQ status register	ISR	R/(W)*2	H'00	H'FF2F
Interrupt priority register A	IPRA	R/W	H'77	H'FEC4
Interrupt priority register B	IPRB	R/W	H'77	H'FEC5
Interrupt priority register C	IPRC	R/W	H'77	H'FEC6
Interrupt priority register D	IPRD	R/W	H'77	H'FEC7
Interrupt priority register E	IPRE	R/W	H'77	H'FEC8
Interrupt priority register F	IPRF	R/W	H'77	H'FEC9
Interrupt priority register G	IPRG	R/W	H'77	H'FECA
Interrupt priority register H	IPRH	R/W	H'77	H'FECB
Interrupt priority register I	IPRI	R/W	H'77	H'FECC
Interrupt priority register J	IPRJ	R/W	H'77	H'FECD
Interrupt priority register K	IPRK	R/W	H'77	H'FECE

Notes: 1. Lower 16 bits of the address.

2. Can only be written with 0 for flag clearing.

5.2 Register Descriptions

5.2.1 System Control Register (SYSCR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	INTM1	INTM0	NMIEG	_	_	RAME
Initial value:		0	0	0	0	0	0	0	1
R/W	:	R/W	_	R/W	R/W	R/W	*	R/W	R/W

Note: * R/W in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398.

SYSCR is an 8-bit readable/writable register that selects the interrupt control mode, and the detected edge for NMI.

Only bits 5 to 3 are described here; for details of the other bits, see section 3.2.2, System Control Register (SYSCR).

SYSCR is initialized to H'01 by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bits 5 and 4—Interrupt Control Mode 1 and 0 (INTM1, INTM0): These bits select one of two interrupt control modes for the interrupt controller.

Bit 5 INTM1	Bit 4 INTM0	Interrupt Control Mode	Description	
0	0	0	Interrupts are controlled by I bit (Initial value	ıe)
	1	_	Setting prohibited	
1	0	2	Interrupts are controlled by bits I2 to I0, and IPR	
	1	_	Setting prohibited	

Bit 3—NMI Edge Select (NMIEG): Selects the input edge for the NMI pin.

Bit 3		
NMIEG	Description	
0	Interrupt request generated at falling edge of NMI input	(Initial value)
1	Interrupt request generated at rising edge of NMI input	

5.2.2 Interrupt Priority Registers A to K (IPRA to IPRK)

Bit	:	7	6	5	4	3	2	1	0
			IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0
Initial va	alue :	0	1	1	1	0	1	1	1
R/W	:		R/W	R/W	R/W	_	R/W	R/W	R/W

The IPR registers are eleven 8-bit readable/writable registers that set priorities (levels 7 to 0) for interrupts other than NMI.

The correspondence between IPR settings and interrupt sources is shown in table 5-3.

The IPR registers set a priority (level 7 to 0) for each interrupt source other than NMI.

The IPR registers are initialized to H'77 by a reset and in hardware standby mode.

Bits 7 and 3—Reserved: These bits cannot be modified and are always read as 0.

Table 5-3 Correspondence between Interrupt Sources and IPR Settings

	Bits						
Register	6 to 4	2 to 0					
IPRA	IRQ0	IRQ1					
IPRB	IRQ2 IRQ3	IRQ4 IRQ5					
IPRC	IRQ6 IRQ7	DTC					
IPRD	Watchdog timer	Refresh timer					
IPRE	*	A/D converter					
IPRF	TPU channel 0	TPU channel 1					
IPRG	TPU channel 2	TPU channel 3					
IPRH	TPU channel 4	TPU channel 5					
IPRI	8-bit timer channel 0	8-bit timer channel 1					
IPRJ	DMAC	SCI channel 0					
IPRK	SCI channel 1	SCI channel 2					

Note: * Reserved bits. These bits cannot be modified and are always read as 1.

As shown in table 5-3, multiple interrupts are assigned to one IPR. Setting a value in the range from H'0 to H'7 in the 3-bit groups of bits 6 to 4 and 2 to 0 sets the priority of the corresponding interrupt. The lowest priority level, level 0, is assigned by setting H'0, and the highest priority level, level 7, by setting H'7.

When interrupt requests are generated, the highest-priority interrupt according to the priority levels set in the IPR registers is selected. This interrupt level is then compared with the interrupt mask level set by the interrupt mask bits (I2 to I0) in the extend register (EXR) in the CPU, and if the priority level of the interrupt is higher than the set mask level, an interrupt request is issued to the CPU.

5.2.3 IRQ Enable Register (IER)

IER is an 8-bit readable/writable register that controls enabling and disabling of interrupt requests IRQ7 to IRQ0.

Bit	:	7	6	5	4	3	2	1	0
		IRQ7E	IRQ6E	IRQ5E	IRQ4E	IRQ3E	IRQ2E	IRQ1E	IRQ0E
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

IER is initialized to H'00 by a reset and in hardware standby mode.

Bits 7 to 0—IRQ7 to IRQ0 Enable (IRQ7E to IRQ0E): These bits select whether IRQ7 to IRQ0 are enabled or disabled.

Bit n IRQnE	Description	
0	IRQn interrupts disabled	(Initial value)
1	IRQn interrupts enabled	
-		(n = 7 to 0)

5.2.4 IRQ Sense Control Registers H and L (ISCRH, ISCRL)

ISCRH

Bit :	15	14	13	12	11	10	9	8
	IRQ7SCB	IRQ7SCA	IRQ6SCB	IRQ6SCA	IRQ5SCB	IRQ5SCA	IRQ4SCB	IRQ4SCA
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W							
ISCRL								
Bit :	7	6	5	4	3	2	1	0
	IRQ3SCB	IRQ3SCA	IRQ2SCB	IRQ2SCA	IRQ1SCB	IRQ1SCA	IRQ0SCB	IRQ0SCA
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W							

ISCR registers are 16-bit readable/writable registers that select rising edge, falling edge, or both edge detection, or level sensing, for the input at pins $\overline{IRQ7}$ to $\overline{IRQ0}$.

ISCR registers are initialized to H'0000 by a reset and in hardware standby mode.

Bits 15 to 0: IRQ7 Sense Control A and B (IRQ7SCA, IRQ7SCB) to IRQ0 Sense Control A and B (IRQ0SCA, IRQ0SCB)

Bits 15 to 0

IRQ7SCB to IRQ0SCB	IRQ7SCA to IRQ0SCA	Description
0	0	Interrupt request generated at $\overline{\text{IRQ7}}$ to $\overline{\text{IRQ0}}$ input low level (initial value)
	1	Interrupt request generated at falling edge of IRQ7 to IRQ0 input
1	0	Interrupt request generated at rising edge of IRQ7 to IRQ0 input
	1	Interrupt request generated at both falling and rising edges of IRQ7 to IRQ0 input

5.2.5 IRQ Status Register (ISR)

Bit	:	7	6	5	4	3	2	1	0
		IRQ7F	IRQ6F	IRQ5F	IRQ4F	IRQ3F	IRQ2F	IRQ1F	IRQ0F
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*

Note: *Only 0 can be written, to clear the flag.

ISR is an 8-bit readable/writable register that indicates the status of IRQ7 to IRQ0 interrupt requests.

ISR is initialized to H'00 by a reset and in hardware standby mode.

Bits 7 to 0—IRQ7 to IRQ0 flags (IRQ7F to IRQ0F): These bits indicate the status of IRQ7 to IRQ0 interrupt requests.

Bit n	
IRQnF	Description

- 0 [Clearing conditions] (Initial value)
 - Cleared by reading IRQnF flag when IRQnF = 1, then writing 0 to IRQnF flag
 - When interrupt exception handling is executed when low-level detection is set (IRQnSCB = IRQnSCA = 0) and IRQn input is high
 - When IRQn interrupt exception handling is executed when falling, rising, or both-edge detection is set (IRQnSCB = 1 or IRQnSCA = 1)
 - When the DTC is activated by an IRQn interrupt, and the DISEL bit in MRB of the DTC is cleared to 0
- 1 [Setting conditions]
 - When IRQn input goes low when low-level detection is set (IRQnSCB = IRQnSCA = 0)
 - When a falling edge occurs in IRQn input when falling edge detection is set (IRQnSCB = 0, IRQnSCA = 1)
 - When a rising edge occurs in IRQn input when rising edge detection is set (IRQnSCB = 1, IRQnSCA = 0)
 - When a falling or rising edge occurs in IRQn input when both-edge detection is set (IRQnSCB = IRQnSCA = 1)

(n = 7 to 0)

5.3 Interrupt Sources

Interrupt sources comprise external interrupts (NMI and IRQ7 to IRQ0) and internal interrupts (52 sources).

5.3.1 External Interrupts

There are nine external interrupts: NMI and IRQ7 to IRQ0. Of these, NMI and IRQ2 to IRQ0 can be used to restore the H8S/2357 Series from software standby mode.

NMI Interrupt: NMI is the highest-priority interrupt, and is always accepted by the CPU regardless of the status of the CPU interrupt mask bits. The NMIEG bit in SYSCR can be used to select whether an interrupt is requested at a rising edge or a falling edge on the NMI pin.

The vector number for NMI interrupt exception handling is 7.

IRQ7 to IRQ0 Interrupts: Interrupts IRQ7 to IRQ0 are requested by an input signal at pins $\overline{\text{IRQ7}}$ to $\overline{\text{IRQ0}}$. Interrupts IRQ7 to IRQ0 have the following features:

- Using ISCR, it is possible to select whether an interrupt is generated by a low level, falling edge, rising edge, or both edges, at pins IRQ7 to IRQ0.
- Enabling or disabling of interrupt requests IRQ7 to IRQ0 can be selected with IER.
- The interrupt priority level can be set with IPR.
- The status of interrupt requests IRQ7 to IRQ0 is indicated in ISR. ISR flags can be cleared to 0 by software.

A block diagram of interrupts IRQ7 to IRQ0 is shown in figure 5-2.

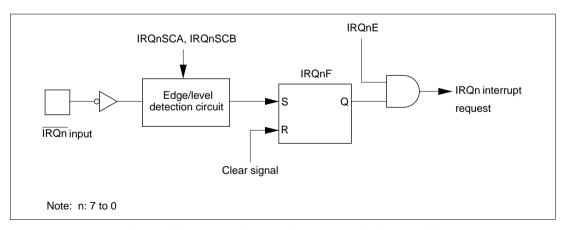


Figure 5-2 Block Diagram of Interrupts IRQ7 to IRQ0

Figure 5-3 shows the timing of setting IRQnF.

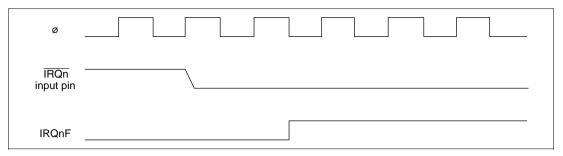


Figure 5-3 Timing of Setting IRQnF

The vector numbers for IRQ7 to IRQ0 interrupt exception handling are 23 to 16.

Detection of IRQ7 to IRQ0 interrupts does not depend on whether the relevant pin has been set for input or output. However, when a pin is used as an external interrupt input pin, do not clear the corresponding DDR to 0 and use the pin as an I/O pin for another function.

5.3.2 Internal Interrupts

There are 52 sources for internal interrupts from on-chip supporting modules.

- For each on-chip supporting module there are flags that indicate the interrupt request status, and enable bits that select enabling or disabling of these interrupts. If both of these are set to 1 for a particular interrupt source, an interrupt request is issued to the interrupt controller.
- The interrupt priority level can be set by means of IPR.
- The DMAC and DTC can be activated by a TPU, SCI, or other interrupt request. When the DMAC or DTC is activated by an interrupt, the interrupt control mode and interrupt mask bits are not affected.

5.3.3 Interrupt Exception Handling Vector Table

Table 5-4 shows interrupt exception handling sources, vector addresses, and interrupt priorities. For default priorities, the lower the vector number, the higher the priority.

Priorities among modules can be set by means of the IPR. The situation when two or more modules are set to the same priority, and priorities within a module, are fixed as shown in table 5-4.

Table 5-4 Interrupt Sources, Vector Addresses, and Interrupt Priorities

	Origin of		Vector Address*		
Interrupt Source	Interrupt Source	Vector Number	Advanced Mode	- IPR	Priority
NMI	External	7	H'001C		High
IRQ0	pin	16	H'0040	IPRA6 to 4	_ 🛉
IRQ1		17	H'0044	IPRA2 to 0	
IRQ2 IRQ3		18 19	H'0048 H'004C	IPRB6 to 4	_
IRQ4 IRQ5	_	20 21	H'0050 H'0054	IPRB2 to 0	_
IRQ6 IRQ7	_	22 23	H'0058 H'005C	IPRC6 to 4	
SWDTEND (software activation interrupt end)	DTC	24	H'0060	IPRC2 to 0	_
WOVI (interval timer)	Watchdog timer	25	H'0064	IPRD6 to 4	_
CMI (compare match)	Refresh controller	26	H'0068	IPRD2 to 0	
Reserved	_	27	H'006C	IPRE6 to 4	_
ADI (A/D conversion end)	A/D	28	H'0070	IPRE2 to 0	
Reserved	_	29 30 31	H'0074 H'0078 H'007C		
TGI0A (TGR0A input capture/ compare match)	TPU channel 0	32	H'0080	IPRF6 to 4	_
TGI0B (TGR0B input capture/ compare match)		33	H'0084		
TGI0C (TGR0C input capture/ compare match)		34	H'0088		
TGI0D (TGR0D input capture/ compare match)		35	H'008C		
TCI0V (overflow 0)		36	H'0090	_	
Reserved	_	37 38	H'0094 H'0098		
		39	H'009C		Low

	Origin of		Vector Address*		
Interrupt Source	Interrupt Source	Vector Number	Advanced Mode	- IPR	Priority
TGI1A (TGR1A input capture/ compare match)	TPU channel 1	40	H'00A0	IPRF2 to 0	High
TGI1B (TGR1B input capture/ compare match)		41	H'00A4		
TCI1V (overflow 1)		42	H'00A8		
TCI1U (underflow 1)		43	H'00AC		_
TGI2A (TGR2A input capture/ compare match)	TPU channel 2	44	H'00B0	IPRG6 to 4	
TGI2B (TGR2B input capture/ compare match)		45	H'00B4		
TCI2V (overflow 2)		46	H'00B8		
TCI2U (underflow 2)		47	H'00BC		_
TGI3A (TGR3A input capture/ compare match)	TPU channel 3	48	H'00C0	IPRG2 to 0	
TGI3B (TGR3B input capture/ compare match)		49	H'00C4		
TGI3C (TGR3C input capture/ compare match)		50	H'00C8		
TGI3D (TGR3D input capture/ compare match)		51	H'00CC		
TCI3V (overflow 3)		52	H'00D0	<u></u>	
Reserved	_	53	H'00D4		
		54	H'00D8		
TOLAN (TORAN	TDU	55	H'00DC	IDDI IO (4	_
TGI4A (TGR4A input capture/ compare match)	TPU channel 4	56	H'00E0	IPRH6 to 4	
TGI4B (TGR4B input capture/ compare match)		57	H'00E4		
TCI4V (overflow 4)		58	H'00E8		
TCI4U (underflow 4)		59	H'00EC		_
TGI5A (TGR5A input capture/ compare match)	TPU channel 5	60	H'00F0	IPRH2 to 0	
TGI5B (TGR5B input capture/ compare match)		61	H'00F4		
TCI5V (overflow 5)		62	H'00F8		
TCI5U (underflow 5)		63	H'00FC		Low

	Origin of		Vector Address*		
Interrupt Source	Interrupt Source	Vector Number	Advanced Mode	- IPR	Priority
CMIA0 (compare match A0)	8-bit timer	64	H'0100	IPRI6 to 4	High
CMIB0 (compare match B0)	channel 0	65	H'0104		A
OVI0 (overflow 0)		66	H'0108		
Reserved	_	67	H'010C		
CMIA1 (compare match A1)	8-bit timer	68	H'0110	IPRI2 to 0	
CMIB1 (compare match B1)	channel 1	69	H'0114		
OVI1 (overflow 1)		70	H'0118		
Reserved	_	71	H'011C		
DEND0A (channel 0/channel 0A transfer end)	DMAC	72	H'0120	IPRJ6 to 4	
DEND0B (channel 0B transfer end)		73	H'0124		
DEND1A (channel 1/channel 1A transfer end)		74	H'0128		
DEND1B (channel 1B transfer end)		75	H'012C		
Reserved	_	76	H'0130		
		77 70	H'0134		
		78 79	H'0138 H'013C		
ERI0 (receive error 0)	SCI	80	H'0140	IPRJ2 to 0	_
RXI0 (reception data full 0)	channel 0	81	H'0144		
TXI0 (transmit data empty 0)		82	H'0148		
TEI0 (transmission end 0)		83	H'014C		
ERI1 (receive error 1)	SCI	84	H'0150	IPRK6 to 4	
RXI1 (reception data full 1)	channel 1	85	H'0154		
TXI1 (transmit data empty 1)		86	H'0158		
TEI1 (transmission end 1)		87	H'015C		
ERI2 (receive error 2)	SCI	88	H'0160	IPRK2 to 0	_
RXI2 (reception data full 2)	channel 2	89	H'0164		
TXI2 (transmit data empty 2)		90	H'0168		
TEI2 (transmission end 2)		91	H'016C		Low

Note: * Lower 16 bits of the start address.

5.4 Interrupt Operation

5.4.1 Interrupt Control Modes and Interrupt Operation

Interrupt operations in the H8S/2357 Series differ depending on the interrupt control mode.

NMI interrupts are accepted at all times except in the reset state and the hardware standby state. In the case of IRQ interrupts and on-chip supporting module interrupts, an enable bit is provided for each interrupt. Clearing an enable bit to 0 disables the corresponding interrupt request. Interrupt sources for which the enable bits are set to 1 are controlled by the interrupt controller.

Table 5-5 shows the interrupt control modes.

The interrupt controller performs interrupt control according to the interrupt control mode set by the INTM1 and INTM0 bits in SYSCR, the priorities set in IPR, and the masking state indicated by the I and UI bits in the CPU's CCR, and bits I2 to I0 in EXR.

Table 5-5 Interrupt Control Modes

Interrupt	SYSCR INTM1 INTM0		Priority Setting	Interrupt		
Control Mode			Registers	Mask Bits	Description	
0	0	0	_	I	Interrupt mask control is performed by the I bit.	
_	_	1	_	_	Setting prohibited	
2	1	0	IPR	I2 to I0	8-level interrupt mask control is performed by bits I2 to I0. 8 priority levels can be set with IPR.	
_	_	1	_	_	Setting prohibited	

Figure 5-4 shows a block diagram of the priority decision circuit.

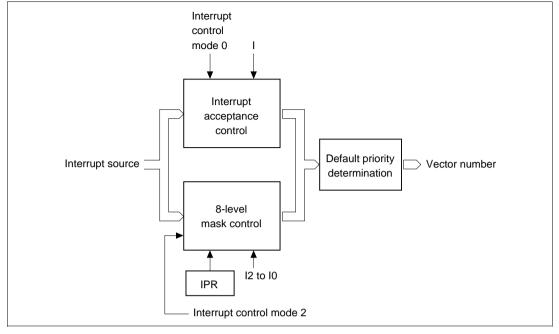


Figure 5-4 Block Diagram of Interrupt Control Operation

(1) Interrupt Acceptance Control

In interrupt control mode 0, interrupt acceptance is controlled by the I bit in CCR.

Table 5-6 shows the interrupts selected in each interrupt control mode.

Table 5-6 Interrupts Selected in Each Interrupt Control Mode (1)

	Interrupt Mask Bits	
Interrupt Control Mode	Ī	Selected Interrupts
0	0	All interrupts
	1	NMI interrupts
2	*	All interrupts

Legend

* : Don't care

(2) 8-Level Control

In interrupt control mode 2, 8-level mask level determination is performed for the selected interrupts in interrupt acceptance control according to the interrupt priority level (IPR).

The interrupt source selected is the interrupt with the highest priority level, and whose priority level set in IPR is higher than the mask level.

Table 5-7 Interrupts Selected in Each Interrupt Control Mode (2)

Interrupt Control Mode	Selected Interrupts
0	All interrupts
2	Highest-priority-level (IPR) interrupt whose priority level is greater than the mask level (IPR > I2 to I0).

(3) Default Priority Determination

When an interrupt is selected by 8-level control, its priority is determined and a vector number is generated.

If the same value is set for IPR, acceptance of multiple interrupts is enabled, and so only the interrupt source with the highest priority according to the preset default priorities is selected and has a vector number generated.

Interrupt sources with a lower priority than the accepted interrupt source are held pending.

Table 5-8 shows operations and control signal functions in each interrupt control mode.

Table 5-8 Operations and Control Signal Functions in Each Interrupt Control Mode

Interrupt Control	Setting		Interrupt Acceptance Control	8-Leve	l Control	Default Priority	т	
Mode	INTM1	INTM0	1	12 to 10	IPR	Determination	(Trace)	
0	0	0	O IM	X —	<u>*2</u>	0	_	
2	1	0	X —*1	\circ IM	PR	0	Т	

Legend

: Interrupt operation control performedX : No operation. (All interrupts enabled)

IM: Used as interrupt mask bit

PR: Sets priority.

—: Not used.

Notes: 1. Set to 1 when interrupt is accepted.

2. Keep the initial setting.

5.4.2 Interrupt Control Mode 0

Enabling and disabling of IRQ interrupts and on-chip supporting module interrupts can be set by means of the I bit in the CPU's CCR. Interrupts are enabled when the I bit is cleared to 0, and disabled when set to 1.

Figure 5-5 shows a flowchart of the interrupt acceptance operation in this case.

- [1] If an interrupt source occurs when the corresponding interrupt enable bit is set to 1, an interrupt request is sent to the interrupt controller.
- [2] The I bit is then referenced. If the I bit is cleared to 0, the interrupt request is accepted. If the I bit is set to 1, only an NMI interrupt is accepted, and other interrupt requests are held pending.
- [3] Interrupt requests are sent to the interrupt controller, the highest-ranked interrupt according to the priority system is accepted, and other interrupt requests are held pending.
- [4] When an interrupt request is accepted, interrupt exception handling starts after execution of the current instruction has been completed.
- [5] The PC and CCR are saved to the stack area by interrupt exception handling. The PC saved on the stack shows the address of the first instruction to be executed after returning from the interrupt handling routine.
- [6] Next, the I bit in CCR is set to 1. This masks all interrupts except NMI.
- [7] A vector address is generated for the accepted interrupt, and execution of the interrupt handling routine starts at the address indicated by the contents of that vector address.

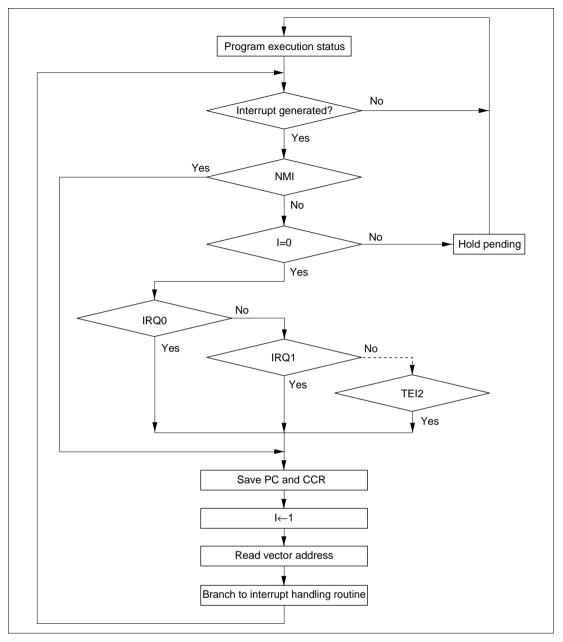


Figure 5-5 Flowchart of Procedure Up to Interrupt Acceptance in Interrupt Control Mode 0

5.4.3 Interrupt Control Mode 2

Eight-level masking is implemented for IRQ interrupts and on-chip supporting module interrupts by comparing the interrupt mask level set by bits I2 to I0 of EXR in the CPU with IPR.

Figure 5-6 shows a flowchart of the interrupt acceptance operation in this case.

- [1] If an interrupt source occurs when the corresponding interrupt enable bit is set to 1, an interrupt request is sent to the interrupt controller.
- [2] When interrupt requests are sent to the interrupt controller, the interrupt with the highest priority according to the interrupt priority levels set in IPR is selected, and lower-priority interrupt requests are held pending. If a number of interrupt requests with the same priority are generated at the same time, the interrupt request with the highest priority according to the priority system shown in table 5-4 is selected.
- [3] Next, the priority of the selected interrupt request is compared with the interrupt mask level set in EXR. An interrupt request with a priority no higher than the mask level set at that time is held pending, and only an interrupt request with a priority higher than the interrupt mask level is accepted.
- [4] When an interrupt request is accepted, interrupt exception handling starts after execution of the current instruction has been completed.
- [5] The PC, CCR, and EXR are saved to the stack area by interrupt exception handling. The PC saved on the stack shows the address of the first instruction to be executed after returning from the interrupt handling routine.
- [6] The T bit in EXR is cleared to 0. The interrupt mask level is rewritten with the priority level of the accepted interrupt.
 - If the accepted interrupt is NMI, the interrupt mask level is set to H'7.
- [7] A vector address is generated for the accepted interrupt, and execution of the interrupt handling routine starts at the address indicated by the contents of that vector address.

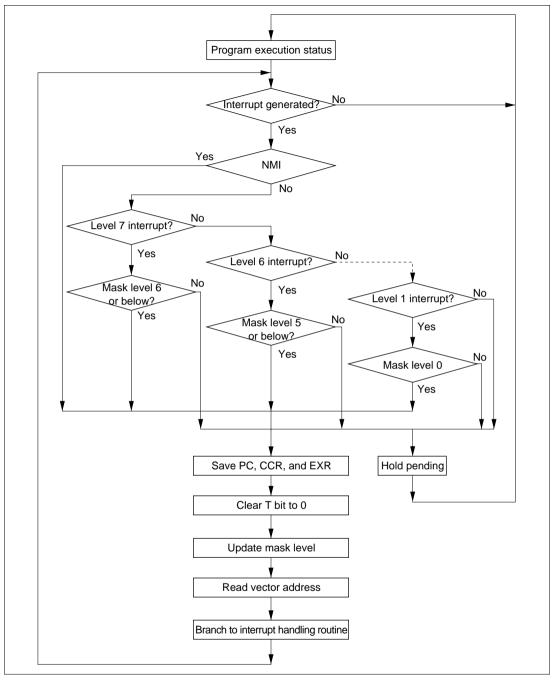


Figure 5-6 Flowchart of Procedure Up to Interrupt Acceptance in Interrupt Control Mode 2

5.4.4 Interrupt Exception Handling Sequence

Figure 5-7 shows the interrupt exception handling sequence. The example shown is for the case where interrupt control mode 0 is set in advanced mode, and the program area and stack area are in on-chip memory.

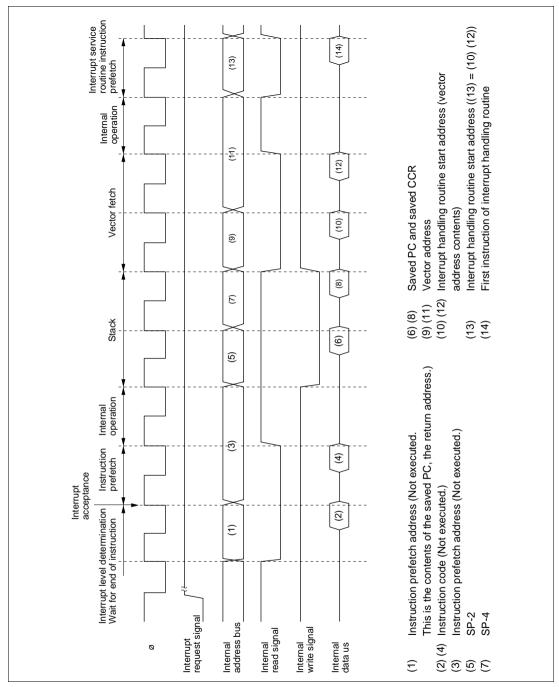


Figure 5-7 Interrupt Exception Handling

5.4.5 Interrupt Response Times

The H8S/2357 Series is capable of fast word transfer instruction to on-chip memory, and the program area is provided in on-chip ROM and the stack area in on-chip RAM, enabling high-speed processing.

Table 5-9 shows interrupt response times - the interval between generation of an interrupt request and execution of the first instruction in the interrupt handling routine. The execution status symbols used in table 5-9 are explained in table 5-10.

Table 5-9 Interrupt Response Times

		Advanced Mode				
No.	Execution Status	INTM1 = 0	INTM1 = 1			
1	Interrupt priority determination*1	3	3			
2	Number of wait states until executing instruction ends*2	1 to (19+2·S _i)	1 to (19+2·S ₁)			
3	PC, CCR, EXR stack save	2·S _K	3⋅S _K			
4	Vector fetch	2·S ₁	2·S ₁			
5	Instruction fetch*3	2·S ₁	2·S ₁			
6	Internal processing*4	2	2			
Total	(using on-chip memory)	12 to 32	13 to 33			

Notes: 1. Two states in case of internal interrupt.

- 2. Refers to MULXS and DIVXS instructions.
- 3. Prefetch after interrupt acceptance and interrupt handling routine prefetch.
- 4. Internal processing after interrupt acceptance and internal processing after vector fetch.

Table 5-10 Number of States in Interrupt Handling Routine Execution Statuses

			Object of Access						
			External Device						
			8 Bit Bus		16 Bit Bus				
Symbol	Internal Memory	2-State Access	3-State Access	2-State Access	3-State Access				
Instruction fetch	Sı	1	4	6+2m	2	3+m			
Branch address read	SJ								
Stack manipulation	Sĸ								

Legend

m : Number of wait states in an external device access.

5.5 Usage Notes

5.5.1 Contention between Interrupt Generation and Disabling

When an interrupt enable bit is cleared to 0 to disable interrupts, the disabling becomes effective after execution of the instruction.

In other words, when an interrupt enable bit is cleared to 0 by an instruction such as BCLR or MOV, if an interrupt is generated during execution of the instruction, the interrupt concerned will still be enabled on completion of the instruction, and so interrupt exception handling for that interrupt will be executed on completion of the instruction. However, if there is an interrupt request of higher priority than that interrupt, interrupt exception handling will be executed for the higher-priority interrupt, and the lower-priority interrupt will be ignored.

The same also applies when an interrupt source flag is cleared.

Figure 5-8 shows an example in which the TGIEA bit in the TPU's TIER0 register is cleared to 0.

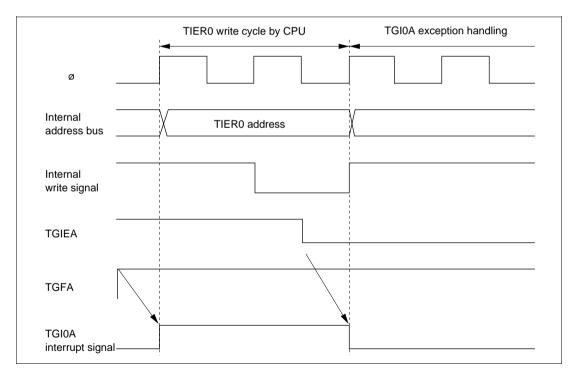


Figure 5-8 Contention between Interrupt Generation and Disabling

The above contention will not occur if an enable bit or interrupt source flag is cleared to 0 while the interrupt is masked.

5.5.2 Instructions that Disable Interrupts

Instructions that disable interrupts are LDC, ANDC, ORC, and XORC. After any of these instructions is executed, all interrupts including NMI are disabled and the next instruction is always executed. When the I bit is set by one of these instructions, the new value becomes valid two states after execution of the instruction ends.

5.5.3 Times when Interrupts are Disabled

There are times when interrupt acceptance is disabled by the interrupt controller.

The interrupt controller disables interrupt acceptance for a 3-state period after the CPU has updated the mask level with an LDC, ANDC, ORC, or XORC instruction.

5.5.4 Interrupts during Execution of EEPMOV Instruction

Interrupt operation differs between the EEPMOV.B instruction and the EEPMOV.W instruction.

With the EEPMOV.B instruction, an interrupt request (including NMI) issued during the transfer is not accepted until the move is completed.

With the EEPMOV.W instruction, if an interrupt request is issued during the transfer, interrupt exception handling starts at a break in the transfer cycle. The PC value saved on the stack in this case is the address of the next instruction.

Therefore, if an interrupt is generated during execution of an EEPMOV.W instruction, the following coding should be used.

L1: EEPMOV.W

MOV.W R4,R4

BNE L1

5.6 DTC and DMAC Activation by Interrupt

5.6.1 Overview

The DTC and DMAC can be activated by an interrupt. In this case, the following options are available:

- Interrupt request to CPU
- Activation request to DTC
- Activation request to DMAC
- Selection of a number of the above

For details of interrupt requests that can be used with to activate the DTC or DMAC, see section 8, Data Transfer Controller, and section 7, DMA Controller.

5.6.2 Block Diagram

Figure 5-9 shows a block diagram of the DTC and DMAC interrupt controller.

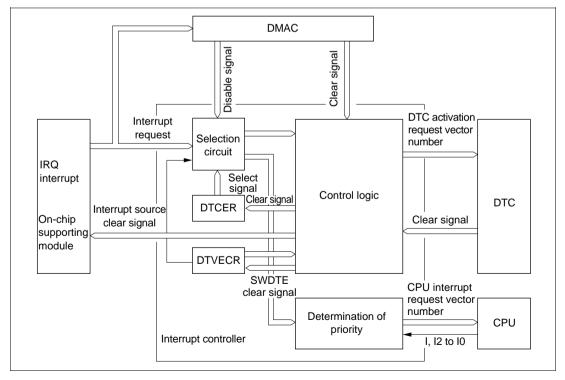


Figure 5-9 Interrupt Control for DTC and DMAC

5.6.3 Operation

The interrupt controller has three main functions in DTC and DMAC control.

(1) **Selection of Interrupt Source:** With the DMAC, the activation source is input directly to each channel. The activation source for each DMAC channel is selected with bits DTF3 to DTF0 in DMACR. Whether the selected activation source is to be managed by the DMAC can be selected with the DTA bit of DMABCR. When the DTA bit is set to 1, the interrupt source constituting that DMAC activation source is not a DTC activation source or CPU interrupt source.

For interrupt sources other than interrupts managed by the DMAC, it is possible to select DTC activation request or CPU interrupt request with the DTCE bit of DTCERA to DTCERF in the DTC.

After a DTC data transfer, the DTCE bit can be cleared to 0 and an interrupt request sent to the CPU in accordance with the specification of the DISEL bit of MRB in the DTC.

When the DTC has performed the specified number of data transfers and the transfer counter value is zero, the DTCE bit is cleared to 0 and an interrupt request is sent to the CPU after the DTC data transfer.

(2) **Determination of Priority:** The DTC activation source is selected in accordance with the default priority order, and is not affected by mask or priority levels. See section 7.6, Interrupts, and section 8.3.3, DTC Vector Table, for the respective priorities.

With the DMAC, the activation source is input directly to each channel.

(3) **Operation Order:** If the same interrupt is selected as a DTC activation source and a CPU interrupt source, the DTC data transfer is performed first, followed by CPU interrupt exception handling.

If the same interrupt is selected as a DMAC activation source and a DTC activation source or CPU interrupt source, operations are performed for them independently according to their respective operating statuses and bus mastership priorities.

Table 5-11 summarizes interrupt source selection and interrupt source clearance control according to the settings of the DTA bit of DMABCR in the DMAC, the DTCE bit of DTCERA to DTCERF in the DTC and the DISEL bit of MRB in the DTC.

Table 5-11 Interrupt Source Selection and Clearing Control

Settings

DMAC	DTC		Interrupt Source Selection/Clearing Control				
DTA	DTCE	DISEL	DMAC	DTC	CPU		
0	0	*	0	Х	Δ		
	1	0	0	Δ	Х		
		1	0	0	Δ		
1	*	*	Δ	Х	Х		

Legend

 $\Delta\,$: The relevant interrupt is used. Interrupt source clearing is performed. (The CPU should clear the source flag in the interrupt handling routine.)

○ : The relevant interrupt is used. The interrupt source is not cleared.

X: The relevant bit cannot be used.

* : Don't care

(4) **Notes on Use:** SCI and A/D converter interrupt sources are cleared when the DMAC or DTC reads or writes to the prescribed register, and are not dependent upon the DTA bit or DISEL bit.

Section 6 Bus Controller

6.1 Overview

The H8S/2357 Series has a built-in bus controller (BSC) that manages the external address space divided into eight areas. The bus specifications, such as bus width and number of access states, can be set independently for each area, enabling multiple memories to be connected easily.

The bus controller also has a bus arbitration function, and controls the operation of the internal bus masters: the CPU, DMA controller (DMAC), and data transfer controller (DTC).

6.1.1 Features

The features of the bus controller are listed below.

- Manages external address space in area units
 - In advanced mode, manages the external space as 8 areas of 2-Mbytes
 - Bus specifications can be set independently for each area
 - DRAM/burst ROM interfaces can be set
- Basic bus interface
 - Chip select ($\overline{CS0}$ to $\overline{CS7}$) can be output for areas 0 to 7
 - 8-bit access or 16-bit access can be selected for each area
 - 2-state access or 3-state access can be selected for each area
 - Program wait states can be inserted for each area
- DRAM interface
 - DRAM interface can be set for areas 2 to 5 (in advanced mode)
 - Row address/column address multiplexed output (8/9/10 bits)
 - Two byte access methods (2-CAS)
 - Burst operation (fast page mode)
 - T_P cycle insertion to secure RAS precharging time
 - Choice of CAS-before-RAS refreshing or self-refreshing
- Burst ROM interface
 - Burst ROM interface can be set for area 0
 - Choice of 1- or 2-state burst access

- Idle cycle insertion
 - An idle cycle can be inserted in case of an external read cycle between different areas
 - An idle cycle can be inserted in case of an external write cycle immediately after an external read cycle
- Write buffer functions
 - External write cycle and internal access can be executed in parallel
 - DMAC single-address mode and internal access can be executed in parallel
- Bus arbitration function
 - Includes a bus arbiter that arbitrates bus mastership among the CPU, DMAC, and DTC
- Other features
 - Refresh counter (refresh timer) can be used as an interval timer
 - External bus release function

6.1.2 Block Diagram

Figure 6-1 shows a block diagram of the bus controller.

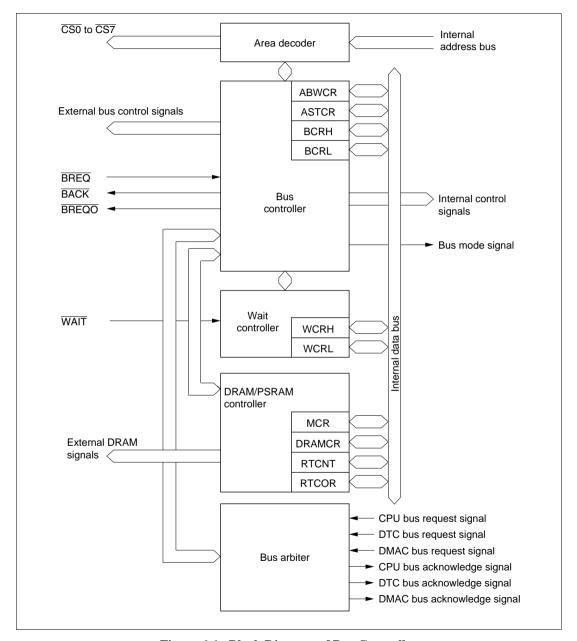


Figure 6-1 Block Diagram of Bus Controller

6.1.3 Pin Configuration

Table 6-1 summarizes the pins of the bus controller.

Table 6-1 Bus Controller Pins

Name	Symbol	I/O	Function
Address strobe	ĀS	Output	Strobe signal indicating that address output on address bus is enabled.
Read	RD	Output	Strobe signal indicating that external space is being read.
High write/write enable	HWR	Output	Strobe signal indicating that external space is to be written, and upper half (D ₁₅ to D ₈) of data bus is enabled. 2-CAS DRAM write enable signal.
Low write	LWR	Output	Strobe signal indicating that external space is to be written, and lower half (D_7 to D_0) of data bus is enabled.
Chip select 0	CS0	Output	Strobe signal indicating that area 0 is selected.
Chip select 1	CS1	Output	Strobe signal indicating that area 1 is selected.
Chip select 2/row address strobe 2	CS2	Output	Strobe signal indicating that area 2 is selected. DRAM row address strobe signal when area 2 is in DRAM space.
Chip select 3/row address strobe 3	CS3	Output	Strobe signal indicating that area 3 is selected. DRAM row address strobe signal when area 3 is in DRAM space.
Chip select 4/row address strobe 4	CS4	Output	Strobe signal indicating that area 4 is selected. DRAM row address strobe signal when area 4 is in DRAM space.
Chip select 5/row address strobe 5	CS5	Output	Strobe signal indicating that area 5 is selected. DRAM row address strobe signal when area 5 is in DRAM space.
Chip select 6	CS6	Output	Strobe signal indicating that area 6 is selected.
Chip select 7	CS7	Output	Strobe signal indicating that area 7 is selected.

Name	Symbol	I/O	Function
Upper column address strobe	CAS	Output	2-CAS DRAM upper column address strobe signal.
Lower column strobe	LCAS	Output	DRAM lower column address strobe signal.
Wait	WAIT	Input	Wait request signal when accessing external 3-state access space.
Bus request	BREQ	Input	Request signal that releases bus to external device.
Bus request acknowledge	BACK	Output	Acknowledge signal indicating that bus has been released.
Bus request output	BREQO	Output	External bus request signal used when internal bus master accesses external space when external bus is released.

6.1.4 Register Configuration

Table 6-2 summarizes the registers of the bus controller.

Table 6-2 Bus Controller Registers

			Initial		
Name	Abbreviation	R/W	Power-On Reset	Manual Reset*3	 Address* ¹
Bus width control register	ABWCR	R/W	H'FF/H'00*2	Retained	H'FED0
Access state control register	ASTCR	R/W	H'FF	Retained	H'FED1
Wait control register H	WCRH	R/W	H'FF	Retained	H'FED2
Wait control register L	WCRL	R/W	H'FF	Retained	H'FED3
Bus control register H	BCRH	R/W	H'D0	Retained	H'FED4
Bus control register L	BCRL	R/W	H'3C	Retained	H'FED5
Memory control register	MCR	R/W	H'00	Retained	H'FED6
DRAM control register	DRAMCR	R/W	H'00	Retained	H'FED7
Refresh timer/counter	RTCNT	R/W	H'00	Retained	H'FED8
Refresh time constant register	RTCOR	R/W	H'FF	Retained	H'FED9

Notes: 1. Lower 16 bits of the address.

- 2. Determined by the MCU operating mode.
- 3. Manual reset is only supported in the H8S/2357 ZTAT version.

6.2 Register Descriptions

6.2.1 Bus Width Control Register (ABWCR)

Bit	:	7	6	5	4	3	2	1	0
		ABW7	ABW6	ABW5	ABW4	ABW3	ABW2	ABW1	ABW0
Modes 5 to	7								
Initial va	lue :	1	1	1	1	1	1	1	1
R/W	:	R/W							
Mode 4									
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

ABWCR is an 8-bit readable/writable register that designates each area for either 8-bit access or 16-bit access.

ABWCR sets the data bus width for the external memory space. The bus width for on-chip memory and internal I/O registers is fixed regardless of the settings in ABWCR.

After a power-on reset and in hardware standby mode, ABWCR is initialized to H'FF in modes 5, and 6, 7,*1 and to H'00 in mode 4. It is not initialized by a manual reset*2 or in software standby mode.

Notes: 1. In ROMless version, modes 6 and 7 are not available.

2. Manual reset is only supported in the H8S/2357 ZTAT version.

Bits 7 to 0—Area 7 to 0 Bus Width Control (ABW7 to ABW0): These bits select whether the corresponding area is to be designated for 8-bit access or 16-bit access.

Bit n ABWn	Description	
0	Area n is designated for 16-bit access	_
1	Area n is designated for 8-bit access	
		(n = 7 to 0)

6.2.2 Access State Control Register (ASTCR)

Bit	:	7	6	5	4	3	2	1	0
		AST7	AST6	AST5	AST4	AST3	AST2	AST1	AST0
Initial va	lue :	1	1	1	1	1	1	1	1
R/W	:	R/W							

ASTCR is an 8-bit readable/writable register that designates each area as either a 2-state access space or a 3-state access space.

ASTCR sets the number of access states for the external memory space. The number of access states for on-chip memory and internal I/O registers is fixed regardless of the settings in ASTCR.

ASTCR is initialized to H'FF by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Bits 7 to 0—Area 7 to 0 Access State Control (AST7 to AST0): These bits select whether the corresponding area is to be designated as a 2-state access space or a 3-state access space.

Wait state insertion is enabled or disabled at the same time.

Bit n ASTn	Description	
0	Area n is designated for 2-state access Wait state insertion in area n external space is disabled	
1	Area n is designated for 3-state access Wait state insertion in area n external space is enabled	(Initial value)
		(n = 7 to 0)

6.2.3 Wait Control Registers H and L (WCRH, WCRL)

WCRH and WCRL are 8-bit readable/writable registers that select the number of program wait states for each area.

Program waits are not inserted in the case of on-chip memory or internal I/O registers.

WCRH and WCRL are initialized to H'FF by a power-on reset and in hardware standby mode. They are not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

(1) WCRH

Bit	:	7	6	5	4	3	2	1	0
		W71	W70	W61	W60	W51	W50	W41	W40
Initial va	alue :	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Bits 7 and 6—Area 7 Wait Control 1 and 0 (W71, W70): These bits select the number of program wait states when area 7 in external space is accessed while the AST7 bit in ASTCR is set to 1.

Bit 7 W71	Bit 6 W70	Description
0	0	Program wait not inserted when external space area 7 is accessed
	1	1 program wait state inserted when external space area 7 is accessed
1	0	2 program wait states inserted when external space area 7 is accessed
	1	3 program wait states inserted when external space area 7 is accessed (Initial value)

Bits 5 and 4—Area 6 Wait Control 1 and 0 (W61, W60): These bits select the number of program wait states when area 6 in external space is accessed while the AST6 bit in ASTCR is set to 1.

Bit 5	Bit 4	~
W61	W60	Description
0	0	Program wait not inserted when external space area 6 is accessed
	1	1 program wait state inserted when external space area 6 is accessed
1	0	2 program wait states inserted when external space area 6 is accessed
	1	3 program wait states inserted when external space area 6 is accessed (Initial value)

Bits 3 and 2—Area 5 Wait Control 1 and 0 (W51, W50): These bits select the number of program wait states when area 5 in external space is accessed while the AST5 bit in ASTCR is set to 1.

Bit 3 W51	Bit 2 W50	Description
0	0	Program wait not inserted when external space area 5 is accessed
	1	1 program wait state inserted when external space area 5 is accessed
1	0	2 program wait states inserted when external space area 5 is accessed
	1	3 program wait states inserted when external space area 5 is accessed (Initial value)

Bits 1 and 0—Area 4 Wait Control 1 and 0 (W41, W40): These bits select the number of program wait states when area 4 in external space is accessed while the AST4 bit in ASTCR is set to 1.

Bit 1 W41	Bit 0 W40	Description
0	0	Program wait not inserted when external space area 4 is accessed
	1	1 program wait state inserted when external space area 4 is accessed
1	0	2 program wait states inserted when external space area 4 is accessed
	1	3 program wait states inserted when external space area 4 is accessed (Initial value)

(2) WCRL

Bit	:	7	6	5	4	3	2	1	0
		W31	W30	W21	W20	W11	W10	W01	W00
Initial va	alue :	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Bits 7 and 6—Area 3 Wait Control 1 and 0 (W31, W30): These bits select the number of program wait states when area 3 in external space is accessed while the AST3 bit in ASTCR is set to 1.

Bit 7 W31	Bit 6 W30	Description
VVSI	WSU	Description
0	0	Program wait not inserted when external space area 3 is accessed
	1	1 program wait state inserted when external space area 3 is accessed
1	0	2 program wait states inserted when external space area 3 is accessed
	1	3 program wait states inserted when external space area 3 is accessed (Initial value)

Bits 5 and 4—Area 2 Wait Control 1 and 0 (W21, W20): These bits select the number of program wait states when area 2 in external space is accessed while the AST2 bit in ASTCR is set to 1.

Bit 5 W21	Bit 4 W20	Description
0	0	Program wait not inserted when external space area 2 is accessed
	1	1 program wait state inserted when external space area 2 is accessed
1	0	2 program wait states inserted when external space area 2 is accessed
	1	3 program wait states inserted when external space area 2 is accessed (Initial value)

Bits 3 and 2—Area 1 Wait Control 1 and 0 (W11, W10): These bits select the number of program wait states when area 1 in external space is accessed while the AST1 bit in ASTCR is set to 1.

Bit 3	Bit 2	
W11	W10	Description
0	0	Program wait not inserted when external space area 1 is accessed
	1	1 program wait state inserted when external space area 1 is accessed
1	0	2 program wait states inserted when external space area 1 is accessed
	1	3 program wait states inserted when external space area 1 is accessed (Initial value)

Bits 1 and 0—Area 0 Wait Control 1 and 0 (W01, W00): These bits select the number of program wait states when area 0 in external space is accessed while the AST0 bit in ASTCR is set to 1.

Bit 1 W01	Bit 0 W00	Description
0	0	Program wait not inserted when external space area 0 is accessed
	1	1 program wait state inserted when external space area 0 is accessed
1	0	2 program wait states inserted when external space area 0 is accessed
	1	3 program wait states inserted when external space area 0 is accessed (Initial value)

6.2.4 Bus Control Register H (BCRH)

Bit	:	7	6	5	4	3	2	1	0
		ICIS1	ICIS0	BRSTRM	BRSTS1	BRSTS0	RMTS2	RMTS1	RMTS0
Initial va	lue :	1	1	0	1	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

BCRH is an 8-bit readable/writable register that selects enabling or disabling of idle cycle insertion, and the memory interface for areas 2 to 5 and area 0.

BCRH is initialized to H'D0 by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Bit 7—Idle Cycle Insert 1 (ICIS1): Selects whether or not one idle cycle state is to be inserted between bus cycles when successive external read cycles are performed in different areas.

Bit 7 ICIS1	Description
0	Idle cycle not inserted in case of successive external read cycles in different areas
1	Idle cycle inserted in case of successive external read cycles in different areas (Initial value)

Bit 6—Idle Cycle Insert 0 (ICIS0): Selects whether or not one idle cycle state is to be inserted between bus cycles when successive external read and external write cycles are performed.

Bit 6 ICIS0	Description
0	Idle cycle not inserted in case of successive external read and external write cycles
1	Idle cycle inserted in case of successive external read and external write cycles
	(Initial value)

Bit 5—Burst ROM Enable (BRSTRM): Selects whether area 0 is used as a burst ROM interface.

Bit 5 BRSTRM	Description	
0	Area 0 is basic bus interface	(Initial value)
1	Area 0 is burst ROM interface	

Bit 4—Burst Cycle Select 1 (BRSTS1): Selects the number of burst cycles for the burst ROM interface.

Bit 4	
BRSTS1	Description

	2 do di i più di	
0	Burst cycle comprises 1 state	
1	Burst cycle comprises 2 states	(Initial value)

Bit 3—Burst Cycle Select 0 (BRSTS0): Selects the number of words that can be accessed in a burst ROM interface burst access.

Bit 3
BRSTS0 Description

0 Max. 4 words in burst access (Initial value)

1 Max. 8 words in burst access

Bits 2 to 0—RAM Type Select (RMTS2 to RMTS0): These bits select the memory interface for areas 2 to 5 in advanced mode.

When DRAM space is selected, the relevant area is designated as DRAM interface.

Bit 2 RMTS2	Bit 1 RMTS1	Bit 0 RMTS0	Description Area 5	Area 4	Area 3	Area 2
0	0	0	Normal space			_
		1	Normal space			DRAM space
	1	0	Normal space		DRAM space	
		1	DRAM space			
1	_	_	_			

Note: When areas selected in DRAM space are all 8-bit space, the PF₂ pin can be used as an I/O port, BREQO, or WAIT.

6.2.5 Bus Control Register L (BCRL)

Bit	:	7	6	5	4	3	2	1	0
		BRLE	BREQOE	EAE	LCASS	DDS	_	WDBE	WAITE
Initial valu	ie:	0	0	1	1	1	1	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

BCRL is an 8-bit readable/writable register that performs selection of the external bus-released state protocol, the LCAS signal, DMAC single address transfer, enabling or disabling of the write data buffer function, and enabling or disabling of WAIT pin input.

BCRL is initialized to H'3C by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Bit 7—Bus Release Enable (BRLE): Enables or disables external bus release.

Bit 7 BRLE	Description
0	External bus release is disabled. BREQ, BACK, and BREQO can be used as I/O ports. (Initial value)
1	External bus release is enabled.

Bit 6—BREQO Pin Enable (BREQOE): Outputs a signal that requests the external bus master to drop the bus request signal (BREQ) in the external bus release state, when an internal bus master performs an external space access, or when a refresh request is generated.

Bit 6		
BREQOE	Description	
0	BREQO output disabled. BREQO can be used as I/O port.	(Initial value)
1	BREQO output enabled.	

Bit 5—External Address Enable (EAE): Selects whether addresses H'010000 to H'01FFFF*² are to be internal addresses or external addresses.

Bit 5

EAE		
0		Addresses H'010000 to H'01FFFF*² are in on-chip ROM
1		Addresses H'010000 to H'01FFFF*2 are external addresses (external expansion mode) or a reserved area*1 (single-chip mode) (Initial value)
Note:	1.	Reserved areas should not be accessed.
	2.	Addresses H'010000 to H'01FFFF are in the H8S/2357. Addresses H'010000 to H'03FFFF are in the H8S/2398. Addresses H'010000 to H'05FFFF are in the H8S/2395. Addresses H'010000 to H'07FFFF are in the H8S/2396.

Bit 4—LCAS Select (LCASS): Write 0 to this bit when using the DRAM interface. \overline{LCAS} pin used for 2-CAS type DRAM interface \overline{LCAS} signal. \overline{BREQO} output and \overline{WAIT} input cannot be used when \overline{LCAS} signal is used.

Bit 3—DACK Timing Select (DDS): Selects the DMAC single address transfer bus timing for the DRAM interface.

Bit 3 DDS	Description					
0	When DMAC single address transfer is performed in DRAM space, full access is always executed	_				
	DACK signal goes low from T₁ or T₁ cycle					
1	Burst access is possible when DMAC single address transfer is performed in DRA space					
	\overline{DACK} signal goes low from T_{c1} or T_2 cycle (Initial value)	e)				

Bit 2—Reserved: Only 1 should be written to this bit.

Bit 1—Write Data Buffer Enable (WDBE): Selects whether or not the write buffer function is used for an external write cycle or DMAC single address cycle.

Bit 1 WDBE	Description	
0	Write data buffer function not used	(Initial value)
1	Write data buffer function used	

Bit 0—WAIT Pin Enable (WAITE): Selects enabling or disabling of wait input by the $\overline{\text{WAIT}}$ pin.

Bit 0		
WAITE	Description	
0	Wait input by WAIT pin disabled. WAIT pin can be used as I/O port.	(Initial value)
1	Wait input by WAIT pin enabled	

6.2.6 Memory Control Register (MCR)

Bit	:	7	6	5	4	3	2	1	0
		TPC	BE	RCDM	CW2	MXC1	MXC0	RLW1	RLW0
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

MCR is an 8-bit readable/writable register that selects the DRAM strobe control method, number of precharge cycles, access mode, address multiplexing shift size, and the number of wait states inserted during refreshing, when areas 2 to 5 are designated as DRAM interface.

MCR is initialized to H'00 by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Bit 7—TP Cycle Control (TPC): Selects whether a 1-state or 2-state precharge cycle (T_P) is to be used when areas 2 to 5 designated as DRAM space are accessed.

Bit 7		
TPC	Description	
0	1-state precharge cycle is inserted	(Initial value)
1	2-state precharge cycle is inserted	

Bit 6—Burst Access Enable (BE): Selects enabling or disabling of burst access to areas 2 to 5 designated as DRAM space. DRAM space burst access is performed in fast page mode.

Bit 6		
BE	Description	
0	Burst disabled (always full access)	(Initial value)
1	For DRAM space access, access in fast page mode	

Bit 5—RAS Down Mode (RCDM): When areas 2 to 5 are designated as DRAM space and access to DRAM is interrupted, RCDM selects whether the next DRAM access is waited for with the \overline{RAS} signal held low (RAS down mode), or the \overline{RAS} signal is driven high again (RAS up mode).

Bit 5		
RCDM	Description	
0	DRAM interface: RAS up mode selected	(Initial value)
1	DRAM interface: RAS down mode selected	

Bit 4—2-CAS Method Select (CW2): Write 1 to this bit when areas 2 to 5 are designated as 8-bit DRAM space, and 0 otherwise.

Bit 4		
CW2	Description	
0	16-bit DRAM space selected	(Initial value)
1	8-bit DRAM space selected	

Bits 3 and 2—Multiplex Shift Count 1 and 0 (MXC1, MXC0): These bits select the size of the shift to the lower half of the row address in row address/column address multiplexing for the DRAM interface. In burst operation on the DRAM interface, these bits also select the row address to be used for comparison.

Bit 3 MXC1	Bit 2 MXC0	Description
0	0	8-bit shift (Initial value)
		 When 8-bit access space is designated: Row address A₂₃ to A₈ used for comparison
		 When 16-bit access space is designated: Row address A₂₃ to A₉ used for comparison
	1	9-bit shift
		 When 8-bit access space is designated: Row address A₂₃ to A₉ used for comparison
		 When 16-bit access space is designated: Row address A₂₃ to A₁₀ used for comparison
1	0	10-bit shift
		 When 8-bit access space is designated: Row address A₂₃ to A₁₀ used for comparison
		 When 16-bit access space is designated: Row address A₂₃ to A₁₁ used for comparison
	1	_

Bits 1 and 0—Refresh Cycle Wait Control 1 and 0 (RLW1, RLW0): These bits select the number of wait states to be inserted in a DRAM interface CAS-before-RAS refresh cycle. This setting is used for all areas designated as DRAM space. Wait input by the WAIT pin is disabled.

Bit 1 RLW1	Bit 0 RLW0	Description	
0	0	No wait state inserted	(Initial value)
	1	1 wait state inserted	
1	0	2 wait states inserted	
	1	3 wait states inserted	

6.2.7 DRAM Control Register (DRAMCR)

Bit	:	7	6	5	4	3	2	1	0
		RFSHE	RCW	RMODE	CMF	CMIE	CKS2	CKS1	CKS0
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DRAMCR is an 8-bit readable/writable register that selects the DRAM refresh mode and refresh counter clock, and controls the refresh timer.

DRAMCR is initialized to H'00 by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Bit 7—Refresh Control (RFSHE): Selects whether or not refresh control is performed. When refresh control is not performed, the refresh timer can be used as an interval timer.

Bit 7		
RFSHE	Description	
0	Refresh control is not performed	(Initial value)
1	Refresh control is performed	

Bit 6—RAS-CAS Wait (RCW): Controls wait state insertion in DRAM interface CAS-before-RAS refreshing.

RCW	Description	
0	Wait state insertion in CAS-before-RAS refreshing disabled $\overline{\rm RAS}$ falls in $\rm T_{\rm Rr}$ cycle	(Initial value)
1	One wait state inserted in CAS-before-RAS refreshing $\overline{\rm RAS}$ falls in $\rm T_{\rm Rc1}$ cycle	

Bit 5—Refresh Mode (RMODE): When refresh control is performed (RFSHE = 1), this bit selects whether normal refreshing (CAS-before-RAS refreshing for the DRAM interface) or self-refreshing is performed.

Bit 5 RMODE	Description	
0	DRAM interface CAS-before-RAS refreshing used	(Initial value)
1	Self-refreshing used	

Bit 4—Compare Match Flag (CMF): Status flag that indicates a match between the values of RTCNT and RTCOR.

When refresh control is performed (RFSHE = 1), 1 should be written to the CMF bit when writing to DRAMCR.

Bit 4 CMF	Description
0	[Clearing condition] Cleared by reading the CMF flag when CMF = 1, then writing 0 to the CMF flag (Initial value)
1	[Setting condition] Set when RTCNT = RTCOR

Bit 3—Compare Match Interrupt Enable (CMIE): Enables or disables interrupt requests (CMI) by the CMF flag when the CMF flag in DRAMCR is set to 1.

When refresh control is performed (RFSHE = 1), the CMIE bit is always cleared to 0.

Bit 3 CMIE	Description	
0	Interrupt request (CMI) by CMF flag disabled	(Initial value)
1	Interrupt request (CMI) by CMF flag enabled	

Bits 2 to 0—Refresh Counter Clock Select (CKS2 to CKS0): These bits select the clock to be input to RTCNT from among 7 internal clocks obtained by dividing the system clock (ø). When the input clock is selected with bits CKS2 to CKS0, RTCNT begins counting up.

Bit 2 CKS2	Bit 1 CKS1	Bit 0 CKS0	Description	
0	0	0	Count operation disabled	(Initial value)
		1	Count uses ø/2	
	1	0	Count uses ø/8	
		1	Count uses ø/32	
1	0	0	Count uses ø/128	
		1	Count uses ø/512	
	1	0	Count uses ø/2048	
		1	Count uses ø/4096	

6.2.8 Refresh Timer/Counter (RTCNT)

Bit	:	7	6	5	4	3	2	1	0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

RTCNT is an 8-bit readable/writable up-counter.

RTCNT counts up using the internal clock selected by bits CKS2 to CKS0 in DRAMCR.

When RTCNT matches RTCOR (compare match), the CMF flag in DRAMCR is set to 1 and RTCNT is cleared to H'00. If the RFSHE bit in DRAMCR is set to 1 at this time, a refresh cycle is started. Also, if the CMIE bit in DRAMCR is set to 1, a compare match interrupt (CMI) is generated.

RTCNT is initialized to H'00 by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

6.2.9 Refresh Time Constant Register (RTCOR)

Bit	:	7	6	5	4	3	2	1	0
Initial va	alue :	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

RTCOR is an 8-bit readable/writable register that sets the period for compare match operations with RTCNT.

The values of RTCOR and RTCNT are constantly compared, and if they match, the CMF flag in DRAMCR is set to 1 and RTCNT is cleared to H'00.

RTCOR is initialized to HFF by a power-on reset and in hardware standby mode. It is not initialized by a manual reset* or in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

6.3 Overview of Bus Control

6.3.1 Area Partitioning

In advanced mode, the bus controller partitions the 16 Mbytes address space into eight areas, 0 to 7, in 2-Mbyte units, and performs bus control for external space in area units. Figure 6-2 shows an outline of the memory map.

Chip select signals ($\overline{CS0}$ to $\overline{CS7}$) can be output for each area.

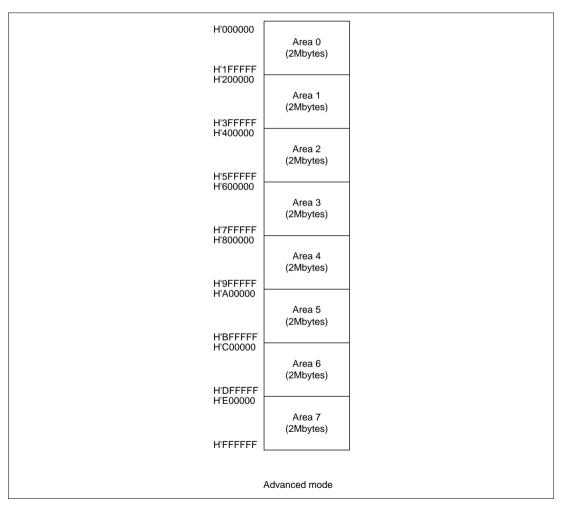


Figure 6-2 Overview of Area Partitioning

6.3.2 Bus Specifications

The external space bus specifications consist of three elements: bus width, number of access states, and number of program wait states.

The bus width and number of access states for on-chip memory and internal I/O registers are fixed, and are not affected by the bus controller.

(1) **Bus Width:** A bus width of 8 or 16 bits can be selected with ADWCR. An area for which an 8-bit bus is selected functions as an 8-bit access space, and an area for which a 16-bit bus is selected functions as a16-bit access space.

If all areas are designated for 8-bit access, 8-bit bus mode is set; if any area is designated for 16-bit access, 16-bit bus mode is set. When the burst ROM interface is designated, 16-bit bus mode is always set.

(2) Number of Access States: Two or three access states can be selected with ASTCR. An area for which 2-state access is selected functions as a 2-state access space, and an area for which 3-state access is selected functions as a 3-state access space.

With the DRAM interface and burst ROM interface, the number of access states may be determined without regard to ASTCR.

When 2-state access space is designated, wait insertion is disabled.

(3) Number of Program Wait States: When 3-state access space is designated by ASTCR, the number of program wait states to be inserted automatically is selected with WCRH and WCRL. From 0 to 3 program wait states can be selected.

Table 6-3 shows the bus specifications for each basic bus interface area.

 Table 6-3
 Bus Specifications for Each Area (Basic Bus Interface)

		WCI	RH, WCRL	Bus Specifications (Basic Bus Interface)							
ABWCR ABWn	ASTCR ASTn	Wn1	Wn0	Bus Width	Access States	Program Wait States					
0	0	_	_	16	2	0					
	1	1 0			3	0					
			1			1					
		1	0			2					
			1			3					
1	0	_	_	8	2	0					
	1	0	0		3	0					
			1			1					
		1	0			2					
			1			3					

6.3.3 Memory Interfaces

The H8S/2357 Series memory interfaces comprise a basic bus interface that allows direct connection of ROM, SRAM, and so on; a DRAM interface that allows direct connection of DRAM; and a burst ROM interface that allows direct connection of burst ROM. The interface can be selected independently for each area.

An area for which the basic bus interface is designated functions as normal space, an area for which the DRAM interface is designated functions as DRAM space, and an area for which the burst ROM interface is designated functions as burst ROM space.

6.3.4 Advanced Mode

The initial state of each area is basic bus interface, 3-state access space. The initial bus width is selected according to the operating mode. The bus specifications described here cover basic items only, and the sections on each memory interface (6.4, 6.5, and 6.7) should be referred to for further details.

Area 0: Area 0 includes on-chip ROM*, and in ROM-disabled expansion mode, all of area 0 is external space. In ROM-enabled expansion mode, the space excluding on-chip ROM* is external space.

When area 0 external space is accessed, the \overline{CSO} signal can be output.

Either basic bus interface or burst ROM interface can be selected for area 0.

Note: * Applies to the On-chip ROM version only.

Areas 1 and 6: In external expansion mode, all of areas 1 and 6 is external space.

When area 1 and 6 external space is accessed, the $\overline{CS1}$ and $\overline{CS6}$ pin signals respectively can be output.

Only the basic bus interface can be used for areas 1 and 6.

Areas 2 to 5: In external expansion mode, all of areas 2 to 5 is external space.

When area 2 to 5 external space is accessed, signals $\overline{CS2}$ to $\overline{CS5}$ can be output.

Basic bus interface or DRAM interface can be selected for areas 2 to 5. With the DRAM interface, signals $\overline{CS2}$ to $\overline{CS5}$ are used as \overline{RAS} signals.

Area 7: Area 7 includes the on-chip RAM and internal I/O registers. In external expansion mode, the space excluding the on-chip RAM and internal I/O registers is external space. The on-chip RAM is enabled when the RAME bit in the system control register (SYSCR) is set to 1; when the RAME bit is cleared to 0, the on-chip RAM is disabled and the corresponding space becomes external space.

When area 7 external space is accessed, the $\overline{CS7}$ signal can be output.

Only the basic bus interface can be used for the area 7 memory interface.

6.3.5 Chip Select Signals

The H8S/2357 Series can output chip select signals ($\overline{CS0}$ to $\overline{CS7}$) to areas 0 to 7, the signal being driven low when the corresponding external space area is accessed.

Figure 6-3 shows an example of \overline{CSn} (n = 0 to 7) output timing.

Enabling or disabling of the \overline{CSn} signal is performed by setting the data direction register (DDR) for the port corresponding to the particular \overline{CSn} pin.

In ROM-disabled expansion mode, the \overline{CSO} pin is placed in the output state after a power-on reset. Pins $\overline{CS1}$ to $\overline{CS7}$ are placed in the input state after a power-on reset, and so the corresponding DDR should be set to 1 when outputting signals $\overline{CS1}$ to $\overline{CS7}$.

In the ROM-enabled expansion mode, pins $\overline{CS0}$ to $\overline{CS7}$ are all placed in the input state after a power-on reset, and so the corresponding DDR bits should be set to 1 when outputting signals $\overline{CS0}$ to $\overline{CS7}$.

For details, see section 9, I/O Ports.

When areas 2 to 5 are designated as DRAM space, outputs $\overline{CS2}$ to $\overline{CS5}$ are used as \overline{RAS} signals.

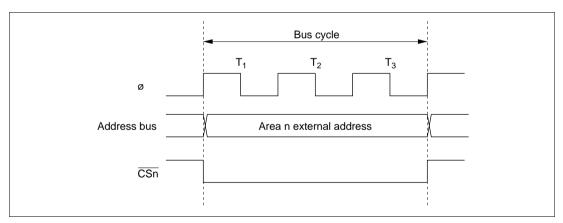


Figure 6-3 \overline{CSn} Signal Output Timing (n = 0 to 7)

6.4 Basic Bus Interface

6.4.1 Overview

The basic bus interface enables direct connection of ROM, SRAM, and so on.

The bus specifications can be selected with ABWCR, ASTCR, WCRH, and WCRL (see table 6-3).

6.4.2 Data Size and Data Alignment

Data sizes for the CPU and other internal bus masters are byte, word, and longword. The bus controller has a data alignment function, and when accessing external space, controls whether the upper data bus (D_{15} to D_{8}) or lower data bus (D_{7} to D_{0}) is used according to the bus specifications for the area being accessed (8-bit access space or 16-bit access space) and the data size.

8-Bit Access Space: Figure 6-4 illustrates data alignment control for the 8-bit access space. With the 8-bit access space, the upper data bus (D_{15} to D_8) is always used for accesses. The amount of data that can be accessed at one time is one byte: a word transfer instruction is performed as two byte accesses, and a longword transfer instruction, as four byte accesses.

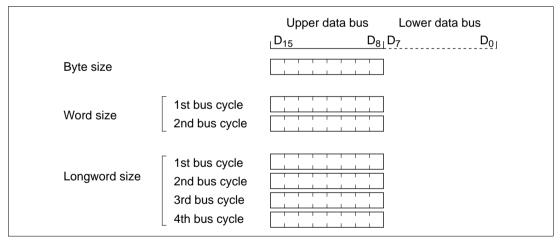


Figure 6-4 Access Sizes and Data Alignment Control (8-Bit Access Space)

16-Bit Access Space: Figure 6-5 illustrates data alignment control for the 16-bit access space. With the 16-bit access space, the upper data bus (D_{15} to D_{8}) and lower data bus (D_{7} to D_{0}) are used for accesses. The amount of data that can be accessed at one time is one byte or one word, and a longword transfer instruction is executed as two word transfer instructions.

In byte access, whether the upper or lower data bus is used is determined by whether the address is even or odd. The upper data bus is used for an even address, and the lower data bus for an odd address.

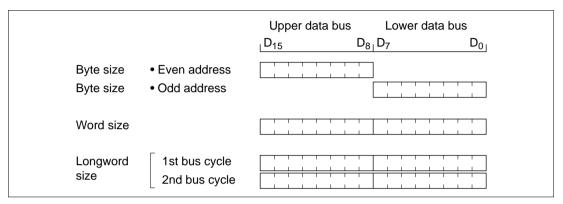


Figure 6-5 Access Sizes and Data Alignment Control (16-Bit Access Space)

6.4.3 Valid Strobes

Table 6-4 shows the data buses used and valid strobes for the access spaces.

In a read, the \overline{RD} signal is valid without discrimination between the upper and lower halves of the data bus.

In a write, the \overline{HWR} signal is valid for the upper half of the data bus, and the \overline{LWR} signal for the lower half.

Table 6-4 Data Buses Used and Valid Strobes

Area	Access Size	Read/ Write	Address	Valid Strobe	Upper Data Bus (D ₁₅ to D ₈)	Lower data bus (D ₇ to D ₀)		
8-bit access	Byte	Read	— RD Valid			Invalid		
space		Write	_	HWR	_	Hi-Z		
16-bit access	Byte	Read	Even	RD	Valid	Invalid		
space			Odd	_	Invalid	Valid		
		Write	Even	HWR	Valid	Hi-Z		
			Odd	LWR	Hi-Z	Valid		
	Word	Read	_	RD	Valid	Valid		
		Write	_	HWR, LWR	Valid	Valid		

Note: Hi-Z: High impedance

Invalid: Input state; input value is ignored.

6.4.4 Basic Timing

8-Bit 2-State Access Space: Figure 6-6 shows the bus timing for an 8-bit 2-state access space. When an 8-bit access space is accessed, the upper half $(D_{15} \text{ to } D_8)$ of the data bus is used.

The \overline{LWR} pin is fixed high. Wait states cannot be inserted.

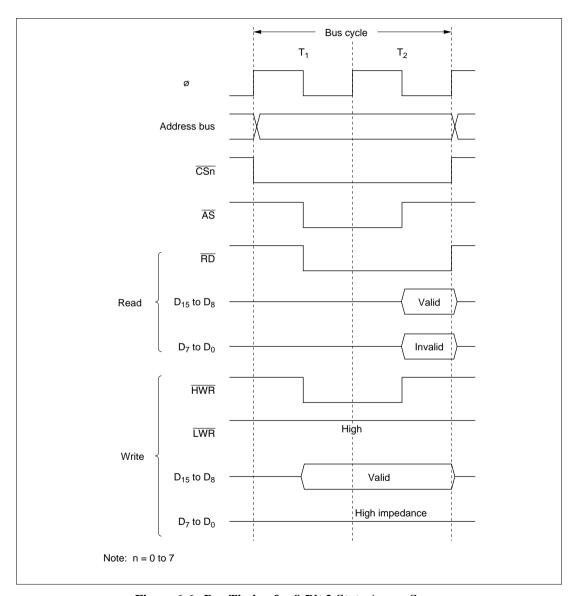


Figure 6-6 Bus Timing for 8-Bit 2-State Access Space

8-Bit 3-State Access Space: Figure 6-7 shows the bus timing for an 8-bit 3-state access space. When an 8-bit access space is accessed, the upper half $(D_{15} \text{ to } D_8)$ of the data bus is used.

The \overline{LWR} pin is fixed high. Wait states can be inserted.

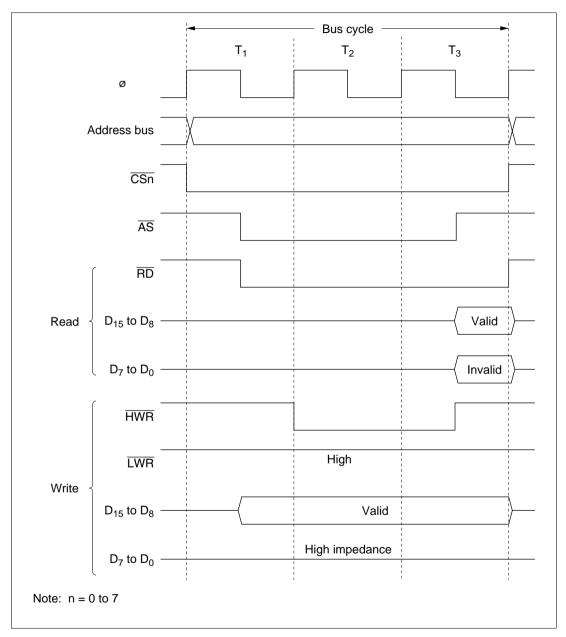


Figure 6-7 Bus Timing for 8-Bit 3-State Access Space

16-Bit 2-State Access Space: Figures 6-8 to 6-10 show bus timings for a 16-bit 2-state access space. When a 16-bit access space is accessed, the upper half (D_{15} to D_{8}) of the data bus is used for the even address, and the lower half (D_{7} to D_{0}) for the odd address.

Wait states cannot be inserted.

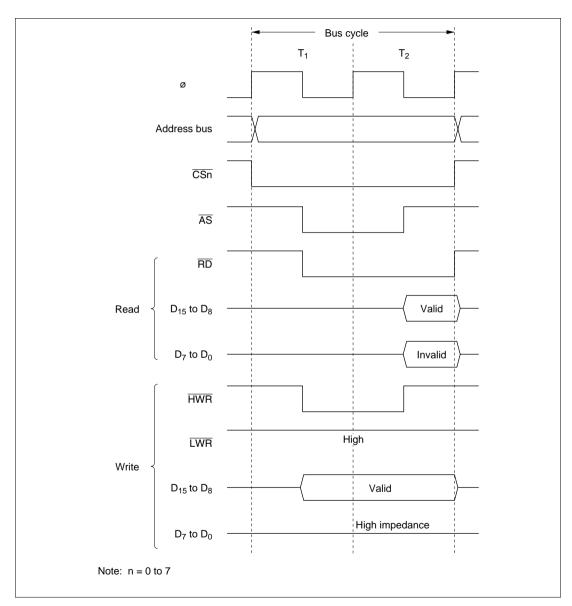


Figure 6-8 Bus Timing for 16-Bit 2-State Access Space (1) (Even Address Byte Access)

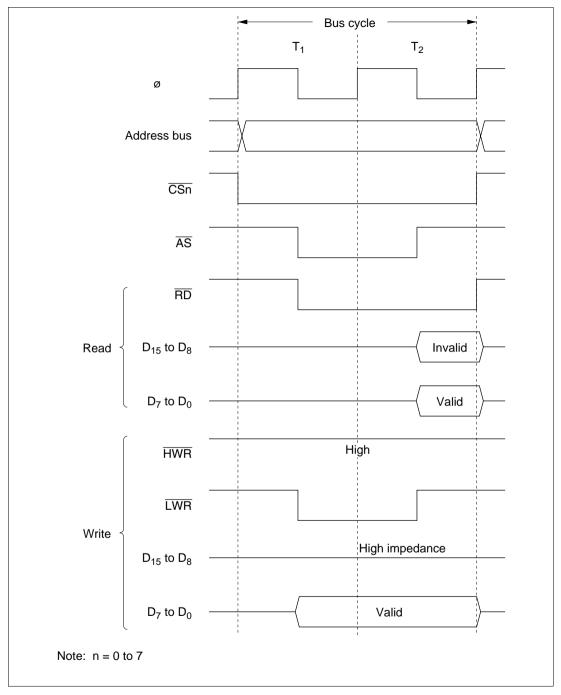


Figure 6-9 Bus Timing for 16-Bit 2-State Access Space (2) (Odd Address Byte Access)

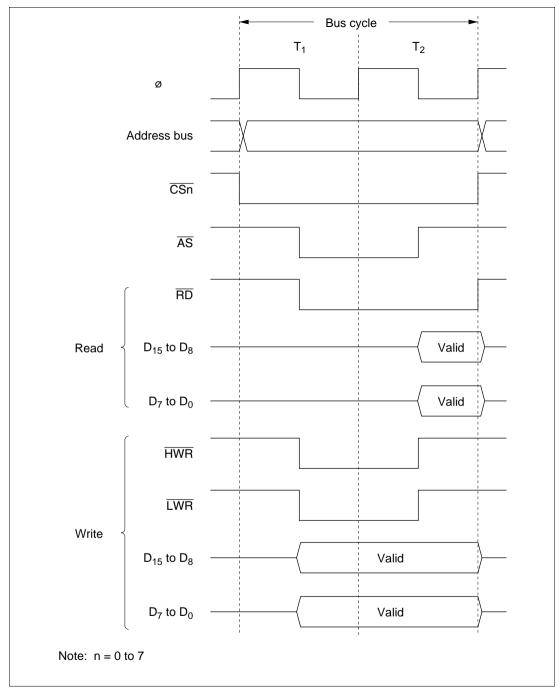


Figure 6-10 Bus Timing for 16-Bit 2-State Access Space (3) (Word Access)

16-Bit 3-State Access Space: Figures 6-11 to 6-13 show bus timings for a 16-bit 3-state access space. When a 16-bit access space is accessed, the upper half $(D_{15} \text{ to } D_8)$ of the data bus is used for the even address, and the lower half $(D_7 \text{ to } D_0)$ for the odd address.

Wait states can be inserted.

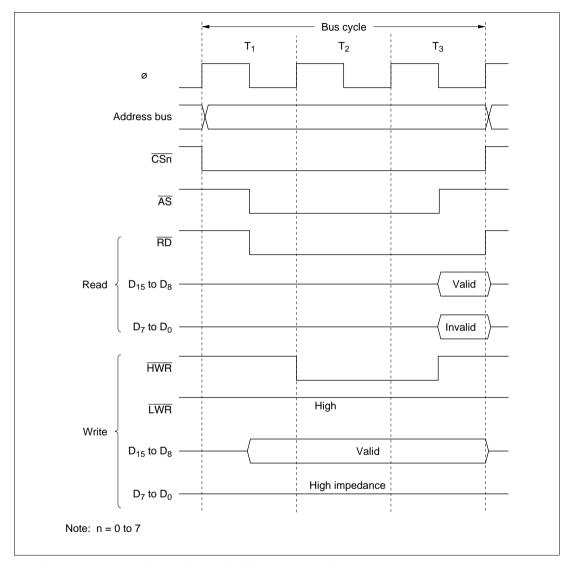


Figure 6-11 Bus Timing for 16-Bit 3-State Access Space (1) (Even Address Byte Access)

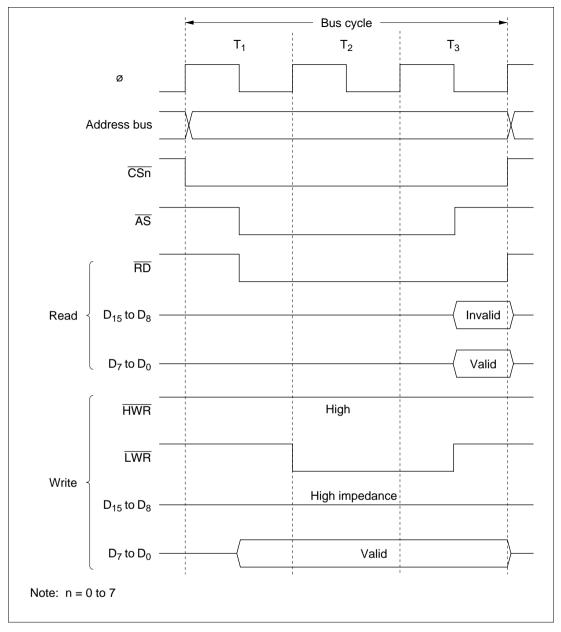


Figure 6-12 Bus Timing for 16-Bit 3-State Access Space (2) (Odd Address Byte Access)

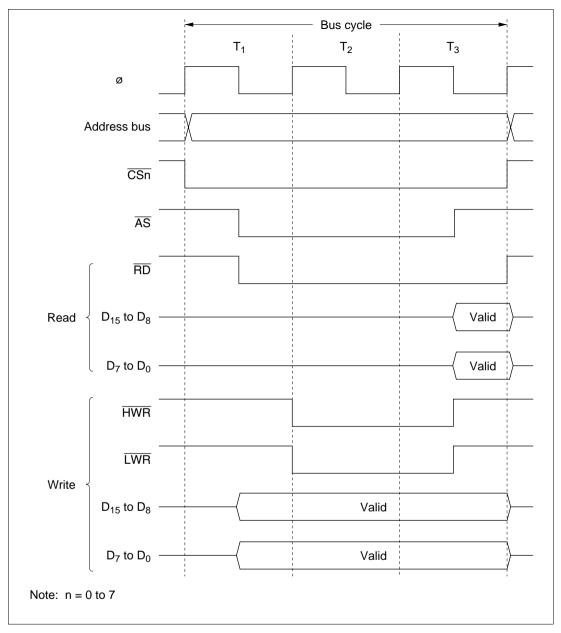


Figure 6-13 Bus Timing for 16-Bit 3-State Access Space (3) (Word Access)

6.4.5 Wait Control

When accessing external space, the H8S/2357 Series can extend the bus cycle by inserting one or more wait states (T_w). There are two ways of inserting wait states: program wait insertion and pin wait insertion using the \overline{WAIT} pin.

Program Wait Insertion

From 0 to 3 wait states can be inserted automatically between the T₂ state and T₃ state on an individual area basis in 3-state access space, according to the settings of WCRH and WCRL.

Pin Wait Insertion

Setting the WAITE bit in BCRL to 1 enables wait insertion by means of the \overline{WAIT} pin. Program wait insertion is first carried out according to the settings in WCRH and WCRL. Then , if the \overline{WAIT} pin is low at the falling edge of ø in the last T_2 or T_w state, a T_w state is inserted. If the \overline{WAIT} pin is held low, T_w states are inserted until it goes high.

This is useful when inserting four or more T_w states, or when changing the number of T_w states for different external devices.

The WAITE bit setting applies to all areas.

Figure 6-14 shows an example of wait state insertion timing.

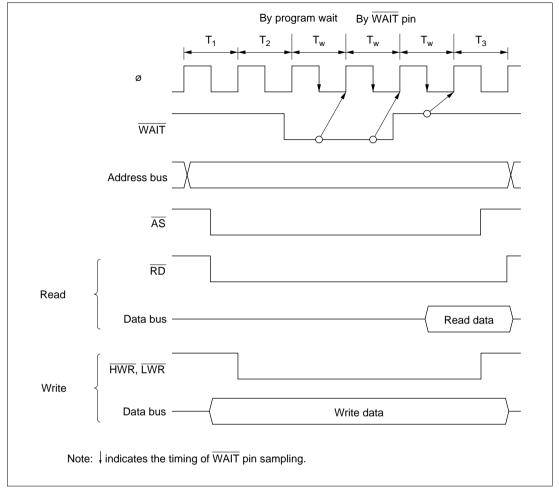


Figure 6-14 Example of Wait State Insertion Timing

The settings after a power-on reset are: 3-state access, 3 program wait state insertion, and WAIT input disabled. When a manual reset* is performed, the contents of bus controller registers are retained, and the wait control settings remain the same as before the reset.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

6.5 DRAM Interface

6.5.1 Overview

When the H8S/2357 Series is in advanced mode, external space areas 2 to 5 can be designated as DRAM space, and DRAM interfacing performed. With the DRAM interface, DRAM can be directly connected to the H8S/2357 Series. A DRAM space of 2, 4, or 8 Mbytes can be set by means of bits RMTS2 to RMTS0 in BCRH. Burst operation is also possible, using fast page mode.

6.5.2 Setting DRAM Space

Areas 2 to 5 are designated as DRAM space by setting bits RMTS2 to RMTS0 in BCRH. The relation between the settings of bits RMTS2 to RMTS0 and DRAM space is shown in table 6-5. Possible DRAM space settings are: one area (area 2), two areas (areas 2 and 3), and four areas (areas 2 to 5).

Table 6-5 Settings of Bits RMTS2 to RMTS0 and Corresponding DRAM Spaces

RMTS2	RMTS1	RMTS0	Area 5	Area 4	Area 3	Area 2
0	0	1	Normal space			DRAM space
	1	0	Normal space		DRAM space	
		1	DRAM space			

6.5.3 Address Multiplexing

With DRAM space, the row address and column address are multiplexed. In address multiplexing, the size of the shift of the row address is selected with bits MXC1 and MXC0 in MCR. Table 6-6 shows the relation between the settings of MXC1 and MXC0 and the shift size.

Table 6-6 Address Multiplexing Settings by Bits MXC1 and MXC0

	MCR		Shift						A	Addr	ess	Pins	6					
	MXC1	MXC0	Size	A ₂₃ to	A ₁₃	A ₁₂	A ₁₁	A ₁₀	A ₉	A ₈	A ₇	A_6	A ₅	A_4	A_3	A ₂	A ₁	A_0
Row address	0	0	8 bits	A ₂₃ to	A ₁₃	A ₂₀	A ₁₉	A ₁₈	A ₁₇	A ₁₆	A ₁₅	A ₁₄	A ₁₃	A ₁₂	A ₁₁	A ₁₀	A_9	A ₈
		1	9 bits	A ₂₃ to	A ₁₃	A ₁₂	A ₂₀	A ₁₉	A ₁₈	A ₁₇	A ₁₆	A ₁₅	A ₁₄	A ₁₃	A ₁₂	A ₁₁	A ₁₀	A_9
	1	0	10 bits	A ₂₃ to	A ₁₃	A ₁₂	A ₁₁	A ₂₀	A ₁₉	A ₁₈	A ₁₇	A ₁₆	A ₁₅	A ₁₄	A ₁₃	A ₁₂	A ₁₁	A ₁₀
		1	Setting prohibited	_		_	_	_	_	_	_	_	_	_	_	_	_	_
Column address		_	_	A ₂₃ to	A ₁₃	A ₁₂	A ₁₁	A ₁₀	A ₉	A ₈	A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀

6.5.4 Data Bus

If the bit in ABWCR corresponding to an area designated as DRAM space is set to 1, that area is designated as 8-bit DRAM space; if the bit is cleared to 0, the area is designated as 16-bit DRAM space. In 16-bit DRAM space, × 16-bit configuration DRAM can be connected directly.

In 8-bit DRAM space the upper half of the data bus, D_{15} to D_8 , is enabled, while in 16-bit DRAM space both the upper and lower halves of the data bus, D_{15} to D_0 , are enabled.

Access sizes and data alignment are the same as for the basic bus interface: see section 6.4.2, Data Size and Data Alignment.

6.5.5 Pins Used for DRAM Interface

Table 6-7 shows the pins used for DRAM interfacing and their functions.

Table 6-7 DRAM Interface Pins

	With DRAM			
Pin	Setting	Name	I/O	Function
HWR	WE	Write enable	Output	When 2-CAS system is set, write enable for DRAM space access.
LCAS	LCAS	Lower column address strobe	Output	Lower column address strobe for 16-bit DRAM space access
CS2	RAS2	Row address strobe 2	Output	Row address strobe when area 2 is designated as DRAM space.
CS3	RAS3	Row address strobe 3	Output	Row address strobe when area 3 is designated as DRAM space.
CS4	RAS4	Row address strobe 4	Output	Row address strobe when area 4 is designated as DRAM space.
CS5	RAS5	Row address strobe 5	Output	Row address strobe when area 5 is designated as DRAM space.
CAS	UCAS	Upper column address strobe	Output	Upper column address strobe for DRAM space access
WAIT	WAIT	Wait	Input	Wait request signal
A ₁₂ to A ₀	A ₁₂ to A ₀	Address pins	Output	Row address/column address multiplexed output
D ₁₅ to D ₀	D_{15} to D_0	Data pins	I/O	Data input/output pins

6.5.6 Basic Timing

Figure 6-15 shows the basic access timing for DRAM space. The basic DRAM access timing is 4 states. Unlike the basic bus interface, the corresponding bits in ASTCR control only enabling or disabling of wait insertion, and do not affect the number of access states. When the corresponding bit in ASTCR is cleared to 0, wait states cannot be inserted in the DRAM access cycle.

The 4 states of the basic timing consist of one T_p (precharge cycle) state, one T_r (row address output cycle), and two T_c (column address output cycle) states, T_{c1} and T_{c2} .

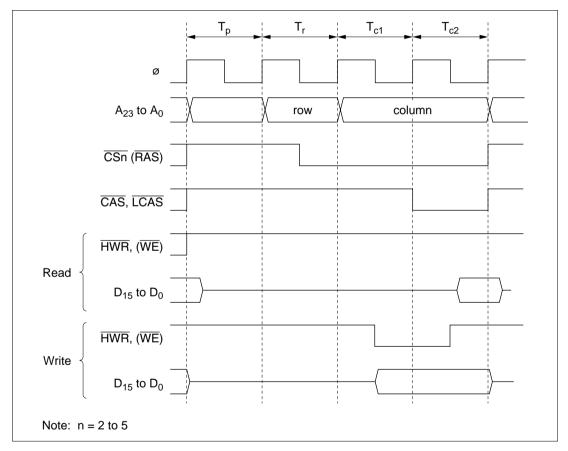


Figure 6-15 Basic Access Timing

6.5.7 Precharge State Control

When DRAM is accessed, RAS precharging time must be secured. With the H8S/2357 Series, one T_p state is always inserted when DRAM space is accessed. This can be changed to two T_p states by setting the TPC bit in MCR to 1. Set the appropriate number of T_p cycles according to the DRAM connected and the operating frequency of the H8S/2357 Series. Figure 6-16 shows the timing when two T_p states are inserted.

When the TPC bit is set to 1, two T_p states are also used for refresh cycles.

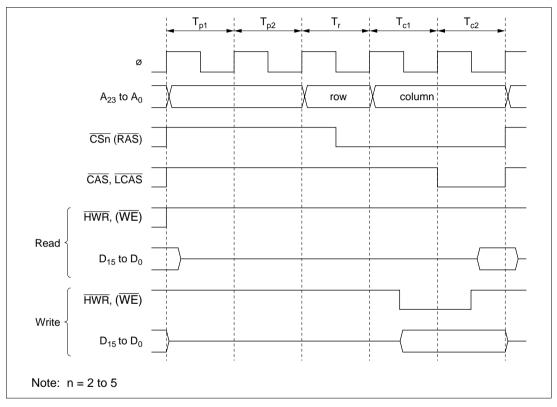


Figure 6-16 Timing with Two Precharge States

6.5.8 Wait Control

There are two ways of inserting wait states in a DRAM access cycle: program wait insertion and pin wait insertion using the \overline{WAIT} pin.

Program Wait Insertion

When the bit in ASTCR corresponding to an area designated as DRAM space is set to 1, from 0 to 3 wait states can be inserted automatically between the $T_{\rm c1}$ state and $T_{\rm c2}$ state, according to the settings of WCRH and WCRL.

Pin Wait Insertion

When the WAITE bit in BCRH is set to 1, wait input by means of the \overline{WAIT} pin is enabled regardless of the setting of the AST bit in ASTCR. When DRAM space is accessed in this state, a program wait is first inserted. If the \overline{WAIT} pin is low at the falling edge of \emptyset in the last T_{c1} or T_w state, another T_w state is inserted. If the \overline{WAIT} pin is held low, T_w states are inserted until it goes high.

Figure 6-17 shows an example of wait state insertion timing.

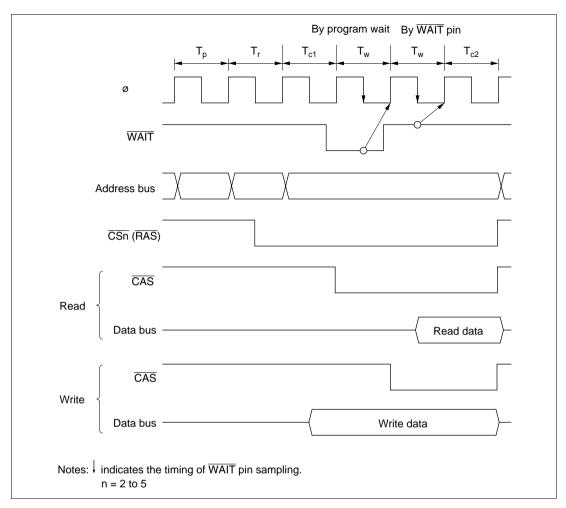


Figure 6-17 Example of Wait State Insertion Timing (CW2 = 1, 8-Bit Area Setting for Entire Space)

6.5.9 Byte Access Control

When DRAM with a $\times 16$ configuration is connected, the 2-CAS system can be used for the control signals required for byte access.

When the CW2 bit is cleared to 0 in MCR, the 2-CAS system is selected. Figure 6-18 shows the control timing in the 2-CAS system, and figure 6-19 shows an example 2-CAS system DRAM connection.

When only DRAM with a ×8 configuration is connected, set the CW2 bit to 1 in MCR.

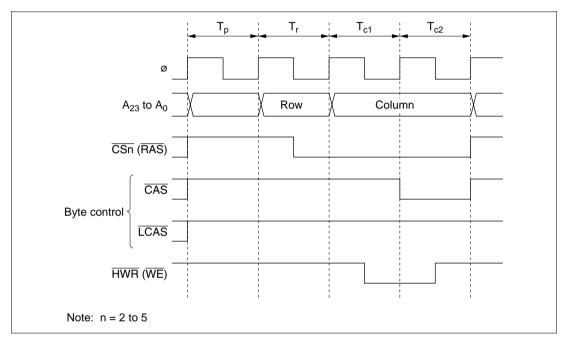


Figure 6-18 2-CAS System Control Timing (Upper Byte Write Access)

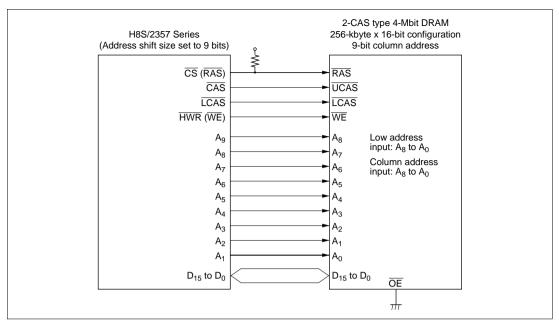


Figure 6-19 Example of 2-CAS System Connection

6.5.10 Burst Operation

With DRAM, in addition to full access (normal access) in which data is accessed by outputting a row address for each access, a fast page mode is also provided which can be used when making a number of consecutive accesses to the same row address. This mode enables fast (burst) access of data by simply changing the column address after the row address has been output. Burst access can be selected by setting the BE bit in MCR to 1.

(1) Burst Access (Fast Page Mode) Operation Timing

Figure 6-20 shows the operation timing for burst access. When there are consecutive access cycles for DRAM space, the \overline{CAS} signal and column address output cycles (two states) continue as long as the row address is the same for consecutive access cycles. The row address used for the comparison is set with bits MXC1 and MXC0 in MCR.

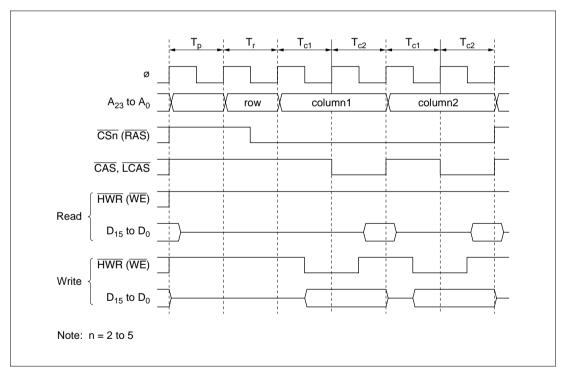


Figure 6-20 Operation Timing in Fast Page Mode

The bus cycle can also be extended in burst access by inserting wait states. The wait state insertion method and timing are the same as for full access. For details, see section 6.5.8, Wait Control.

(2) RAS Down Mode and RAS Up Mode

Even when burst operation is selected, it may happen that access to DRAM space is not continuous, but is interrupted by access to another space. In this case, if the \overline{RAS} signal is held low during the access to the other space, burst operation can be resumed when the same row address in DRAM space is accessed again.

RAS down mode

To select RAS down mode, set the RCDM bit $\overline{\text{in MCR}}$ to 1. If access to DRAM space is interrupted and another space is accessed, the $\overline{\text{RAS}}$ signal is held low during the access to the other space, and burst access is performed if the row address of the next DRAM space access is the same as the row address of the previous DRAM space access. Figure 6-21 shows an example of the timing in RAS down mode.

Note, however, that the \overline{RAS} signal will go high if a refresh operation interrupts RAS down mode.

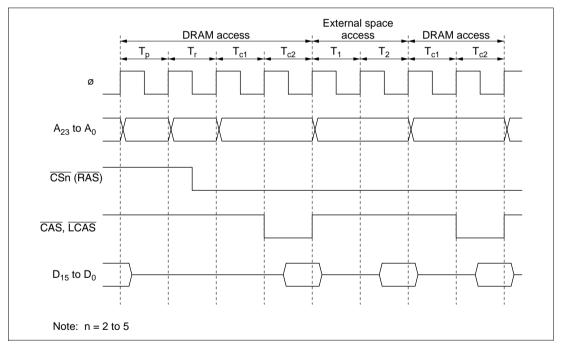


Figure 6-21 Example of Operation Timing in RAS Down Mode

• RAS up mode

To select RAS up mode, clear the RCDM bit in \underline{MCR} to 0. Each time access to DRAM space is interrupted and another space is accessed, the \overline{RAS} signal goes high again. Burst operation is only performed if DRAM space is continuous. Figure 6-22 shows an example of the timing in RAS up mode.

In the case of burst ROM space access, the \overline{RAS} signal is not restored to the high level.

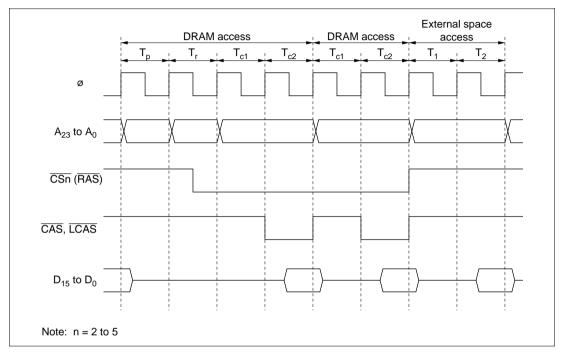


Figure 6-22 Example of Operation Timing in RAS Up Mode

6.5.11 Refresh Control

The H8S/2357 Series is provided with a DRAM refresh control function. Either of two refreshing methods can be selected: CAS-before-RAS (CBR) refreshing, or self-refreshing.

(1) CAS-before-RAS (CBR) Refreshing

To select CBR refreshing, set the RFSHE bit in DRAMCR to 1, and clear the RMODE bit to 0.

With CBR refreshing, RTCNT counts up using the input clock selected by bits CKS2 to CKS0 in DRAMCR, and when the count matches the value set in RTCOR (compare match), refresh control is performed. At the same time, RTCNT is reset and starts counting again from H'00. Refreshing is thus repeated at fixed intervals determined by RTCOR and bits CKS2 to CKS0. Set a value in RTCOR and bits CKS2 to CKS0 that will meet the refreshing interval specification for the DRAM used.

When bits CKS2 to CKS0 are set, RTCNT starts counting up. RTCNT and RTCOR settings should therefore be completed before setting bits CKS2 to CKS0.

Do not clear the CMF flag when refresh control is being performed (RFSHE = 1).

RTCNT operation is shown in figure 6-23, compare match timing in figure 6-24, and CBR refresh timings in figure 6-25.

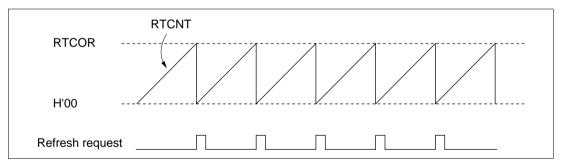


Figure 6-23 RTCNT Operation

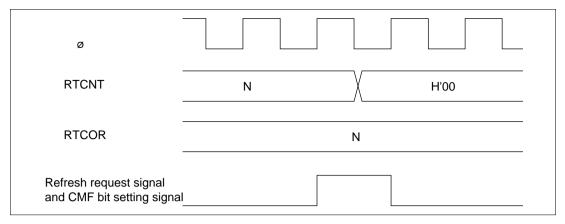


Figure 6-24 Compare Match Timing

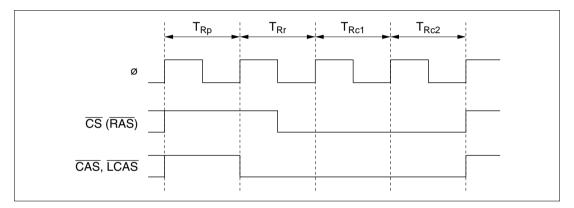


Figure 6-25 CBR Refresh Timing

When the RCW bit is set to 1, \overline{RAS} signal output is delayed by one cycle. The width of the \overline{RAS} signal should be adjusted with bits RLW1 and RLW0. These bits are only enabled in refresh operations.

Figure 6-26 shows the timing when the RCW bit is set to 1.

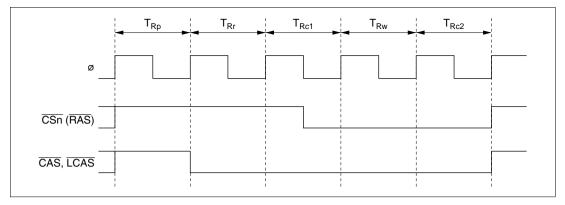


Figure 6-26 CBR Refresh Timing (When RCW = 1, RLW1 = 0, RLW0 = 1)

(2) Self-Refreshing

A self-refresh mode (battery backup mode) is provided for DRAM as a kind of standby mode. In this mode, refresh timing and refresh addresses are generated within the DRAM.

To select self-refreshing, set the RFSHE bit and RMODE bit in DRAMCR to 1. Then, when a SLEEP instruction is executed to enter software standby mode, the \overline{CAS} and \overline{RAS} signals are output and DRAM enters self-refresh mode, as shown in figure 6-27.

When software standby mode is exited, the RMODE bit is cleared to 0 and self-refresh mode is cleared.

When switching to software standby mode, if there is a CBR refresh request, CBR refreshing is executed before self-refresh mode is entered.

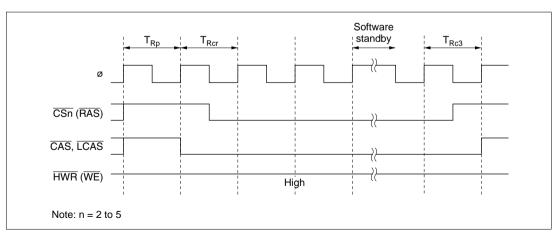


Figure 6-27 Self-Refresh Timing (When CW2 = 1, or CW2 = 0 and LCASS = 0)

6.6 DMAC Single Address Mode and DRAM Interface

When burst mode is selected with the DRAM interface, the \overline{DACK} output timing can be selected with the DDS bit. When DRAM space is accessed in DMAC single address mode at the same time, whether or not burst access is to be performed is selected.

$6.6.1 \qquad \text{When DDS} = 1$

Burst access is performed by determining the address only, irrespective of the bus master. The \overline{DACK} output goes low from the T_{C1} state in the case of the DRAM interface.

Figure 6-28 shows the \overline{DACK} output timing for the DRAM interface when DDS = 1.

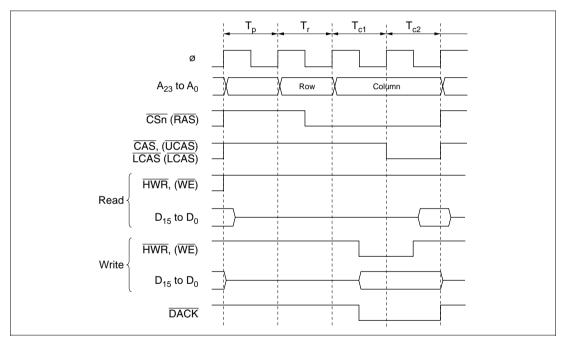


Figure 6-28 DACK Output Timing when DDS = 1 (Example of DRAM Access)

6.6.2 When DDS = 0

When DRAM space is accessed in DMAC single address mode, full access (normal access) is always performed. The \overline{DACK} output goes low from the T_r state in the case of the DRAM interface.

In modes other than DMAC single address mode, burst access can be used when accessing DRAM space.

Figure 6-29 shows the \overline{DACK} output timing for the DRAM interface when DDS = 0.

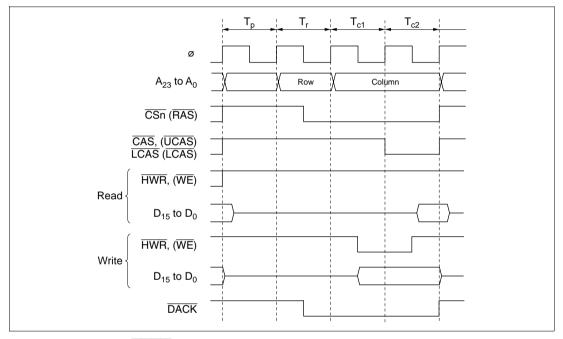


Figure 6-29 \overline{DACK} Output Timing when DDS = 0 (Example of DRAM Access)

6.7 Burst ROM Interface

6.7.1 Overview

With the H8S/2357 Series, external space area 0 can be designated as burst ROM space, and burst ROM interfacing can be performed. The burst ROM space interface enables 16-bit configuration ROM with burst access capability to be accessed at high speed.

Area 0 can be designated as burst ROM space by means of the BRSTRM bit in BCRH. Consecutive burst accesses of a maximum of 4 words or 8 words can be performed for CPU instruction fetches only. One or two states can be selected for burst access.

6.7.2 Basic Timing

The number of states in the initial cycle (full access) of the burst ROM interface is in accordance with the setting of the AST0 bit in ASTCR. Also, when the AST0 bit is set to 1, wait state insertion is possible. One or two states can be selected for the burst cycle, according to the setting of the BRSTS1 bit in BCRH. Wait states cannot be inserted. When area 0 is designated as burst ROM space, it becomes 16-bit access space regardless of the setting of the ABW0 bit in ABWCR.

When the BRSTS0 bit in BCRH is cleared to 0, burst access of up to 4 words is performed; when the BRSTS0 bit is set to 1, burst access of up to 8 words is performed.

The basic access timing for burst ROM space is shown in figures 6-30 (a) and (b). The timing shown in figure 6-30 (a) is for the case where the AST0 and BRSTS1 bits are both set to 1, and that in figure 6-30 (b) is for the case where both these bits are cleared to 0.

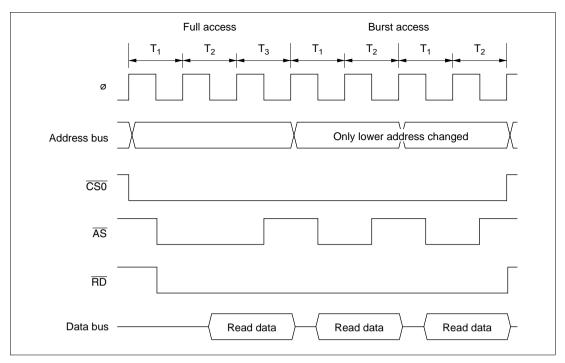


Figure 6-30 (a) Example of Burst ROM Access Timing (When AST0 = BRSTS1 = 1)

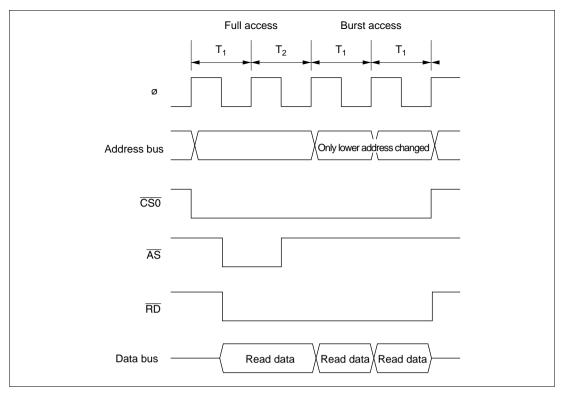


Figure 6-30 (b) Example of Burst ROM Access Timing (When AST0 = BRSTS1 = 0)

6.7.3 Wait Control

As with the basic bus interface, either program wait insertion or pin wait insertion using the \overline{WAIT} pin can be used in the initial cycle (full access) of the burst ROM interface. See section 6.4.5, Wait Control.

Wait states cannot be inserted in a burst cycle.

6.8 Idle Cycle

6.8.1 Operation

When the H8S/2357 Series accesses external space , it can insert a 1-state idle cycle (T_I) between bus cycles in the following two cases: (1) when read accesses between different areas occur consecutively, and (2) when a write cycle occurs immediately after a read cycle. By inserting an idle cycle it is possible, for example, to avoid data collisions between ROM, with a long output floating time, and high-speed memory, I/O interfaces, and so on.

(1) Consecutive Reads between Different Areas

If consecutive reads between different areas occur while the ICIS1 bit in BCRH is set to 1, an idle cycle is inserted at the start of the second read cycle. This is enabled in advanced mode.

Figure 6-31 shows an example of the operation in this case. In this example, bus cycle A is a read cycle from ROM with a long output floating time, and bus cycle B is a read cycle from SRAM, each being located in a different area. In (a), an idle cycle is not inserted, and a collision occurs in cycle B between the read data from ROM and that from SRAM. In (b), an idle cycle is inserted, and a data collision is prevented.

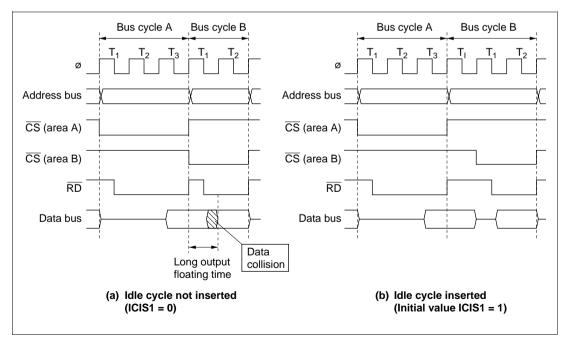


Figure 6-31 Example of Idle Cycle Operation (1)

(2) Write after Read

If an external write occurs after an external read while the ICISO bit in BCRH is set to 1, an idle cycle is inserted at the start of the write cycle.

Figure 6-32 shows an example of the operation in this case. In this example, bus cycle A is a read cycle from ROM with a long output floating time, and bus cycle B is a CPU write cycle. In (a), an idle cycle is not inserted, and a collision occurs in cycle B between the read data from ROM and the CPU write data. In (b), an idle cycle is inserted, and a data collision is prevented.

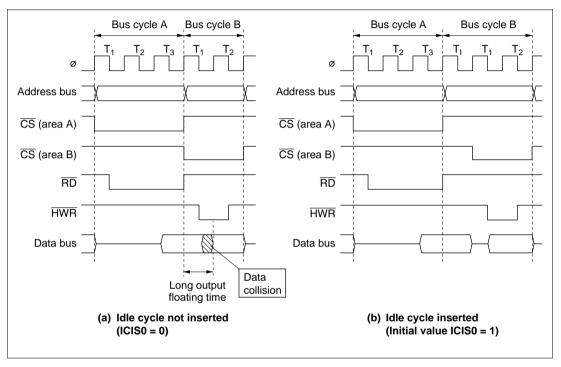


Figure 6-32 Example of Idle Cycle Operation (2)

(3) Relationship between Chip Select (\overline{CS}) Signal and Read (\overline{RD}) Signal

Depending on the system's load conditions, the \overline{RD} signal may lag behind the \overline{CS} signal. An example is shown in figure 6.33.

In this case, with the setting for no idle cycle insertion (a), there may be a period of overlap between the bus cycle A \overline{RD} signal and the bus cycle B \overline{CS} signal.

Setting idle cycle insertion, as in (b), however, will prevent any overlap between the \overline{RD} and \overline{CS} signals.

In the initial state after reset release, idle cycle insertion (b) is set.

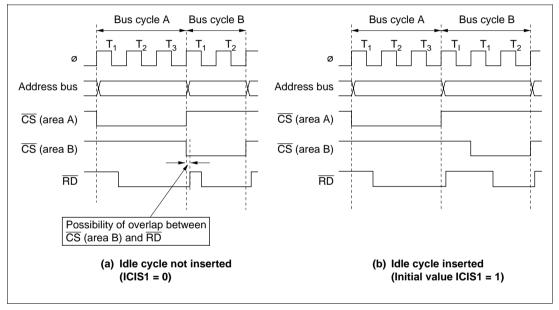


Figure 6.33 Relationship between Chip Select (\overline{CS}) and Read (\overline{RD})

(4) Usage Notes

When DRAM space is accessed, the ICIS0 and ICIS1 bit settings are disabled. In the case of consecutive reads between different areas, for example, if the second access is a DRAM access, only a T_p cycle is inserted, and a T_1 cycle is not. The timing in this case is shown in figure 6-34.

However, in burst access in RAS down mode these settings are enabled, and an idle cycle is inserted. The timing in this case is shown in figures 6-35 (a) and (b).

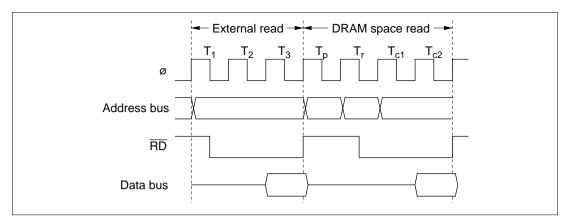


Figure 6-34 Example of DRAM Access after External Read

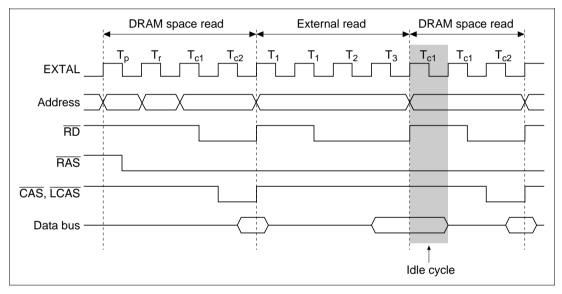


Figure 6-35 (a) Example of Idle Cycle Operation in RAS Down Mode (ICIS1 = 1)

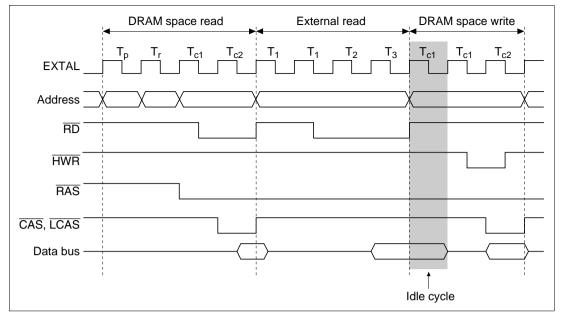


Figure 6-35 (b) Example of Idle Cycle Operation in RAS Down Mode (ICIS0 = 1)

6.8.2 Pin States in Idle Cycle

Table 6-8 shows pin states in an idle cycle.

Table 6-8 Pin States in Idle Cycle

Pins	Pin State
A ₂₃ to A ₀	Contents of next bus cycle
D_{15} to D_{0}	High impedance
CSn ^{∗²}	High* ¹
CAS	High
ĀS	High
RD	High
HWR	High
LWR	High
DACKm*3	High

Note: 1. Remains low in DRAM space RAS down mode or a refresh cycle.

- 2. n = 0 to 7
- 3. m = 0, 1

6.9 Write Data Buffer Function

The H8S/2357 Series has a write data buffer function in the external data bus. Using the write data buffer function enables external writes and DMA single address mode transfers to be executed in parallel with internal accesses. The write data buffer function is made available by setting the WDBE bit in BCRL to 1.

Figure 6-36 shows an example of the timing when the write data buffer function is used. When this function is used, if an external write or DMA single address mode transfer continues for 2 states or longer, and there is an internal access next, only an external write is executed in the first state, but from the next state onward an internal access (on-chip memory or internal I/O register read/write) is executed in parallel with the external write rather than waiting until it ends.

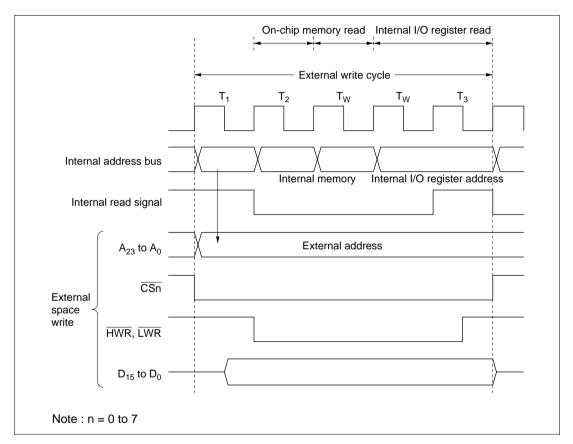


Figure 6-36 Example of Timing when Write Data Buffer Function is Used

6.10 Bus Release

6.10.1 Overview

The H8S/2357 Series can release the external bus in response to a bus request from an external device. In the external bus released state, the internal bus master continues to operate as long as there is no external access.

If an internal bus master wants to make an external access in the external bus released state, or if a refresh request is generated, it can issue a bus request off-chip.

6.10.2 Operation

In external expansion mode, the bus can be released to an external device by setting the BRLE bit in BCRL to 1. Driving the \overline{BREQ} pin low issues an external bus request to the H8S/2357 Series. When the \overline{BREQ} pin is sampled, at the prescribed timing the \overline{BACK} pin is driven low, and the address bus, data bus, and bus control signals are placed in the high-impedance state, establishing the external bus-released state.

In the external bus released state, an internal bus master can perform accesses using the internal bus. When an internal bus master wants to make an external access, it temporarily defers activation of the bus cycle, and waits for the bus request from the external bus master to be dropped. Even if a refresh request is generated in the external bus released state, refresh control is deferred until the external bus master drops the bus request.

If the BREQOE bit in BCRL is set to 1, when an internal bus master wants to make an external access in the external bus released state, or when a refresh request is generated, the BREQO pin is driven low and a request can be made off-chip to drop the bus request.

When the \overline{BREQ} pin is driven high, the \overline{BACK} pin is driven high at the prescribed timing and the external bus released state is terminated.

If an external bus release request and external access occur simultaneously, the order of priority is as follows:

(High) External bus release > Internal bus master external access (Low)

If a refresh request and external bus release request occur simultaneously, the order of priority is as follows:

(High) Refresh > External bus release (Low)

As a refresh and an external access by an internal bus master can be executed simultaneously, there is no relative order of priority for these two operations.

6.10.3 Pin States in External Bus Released State

Table 6-9 shows pin states in the external bus released state.

Table 6-9 Pin States in Bus Released State

Pins	Pin State
A ₂₃ to A ₀	High impedance
D ₁₅ to D ₀	High impedance
CSn ^{∗¹}	High impedance
CAS	High impedance
ĀS	High impedance
RD	High impedance
HWR	High impedance
LWR	High impedance
DACKm*2	High

Notes: 1. n = 0 to 7

2. m = 0, 1

6.10.4 Transition Timing

Figure 6-37 shows the timing for transition to the bus-released state.

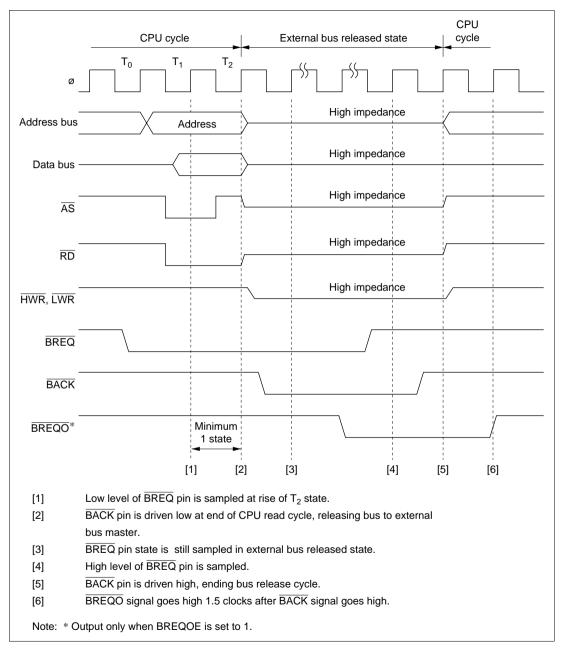


Figure 6-37 Bus-Released State Transition Timing

6.10.5 Usage Note

When MSTPCR is set to H'FFFF or H'EFFF and a transition is made to sleep mode, the external bus release function halts. Therefore, MSTPCR should not be set to H'FFFF or H'EFFF if the external bus release function is to be used in sleep mode.

6.11 Bus Arbitration

6.11.1 Overview

The H8S/2357 Series has a bus arbiter that arbitrates bus master operations.

There are three bus masters, the CPU, DTC, and DMAC, which perform read/write operations when they have possession of the bus. Each bus master requests the bus by means of a bus request signal. The bus arbiter determines priorities at the prescribed timing, and permits use of the bus by means of a bus request acknowledge signal. The selected bus master then takes possession of the bus and begins its operation.

6.11.2 Operation

The bus arbiter detects the bus masters' bus request signals, and if the bus is requested, sends a bus request acknowledge signal to the bus master making the request. If there are bus requests from more than one bus master, the bus request acknowledge signal is sent to the one with the highest priority. When a bus master receives the bus request acknowledge signal, it takes possession of the bus until that signal is canceled.

The order of priority of the bus masters is as follows:

An internal bus access by an internal bus master, external bus release, and refreshing, can be executed in parallel.

In the event of simultaneous external bus release request, refresh request, and internal bus master external access request generation, the order of priority is as follows:

```
(High) Refresh > External bus release (Low)
```

(High) External bus release > Internal bus master external access (Low)

As a refresh and an external access by an internal bus master can be executed simultaneously, there is no relative order of priority for these two operations.

6.11.3 Bus Transfer Timing

Even if a bus request is received from a bus master with a higher priority than that of the bus master that has acquired the bus and is currently operating, the bus is not necessarily transferred immediately. There are specific times at which each bus master can relinquish the bus.

CPU: The CPU is the lowest-priority bus master, and if a bus request is received from the DTC or DMAC, the bus arbiter transfers the bus to the bus master that issued the request. The timing for transfer of the bus is as follows:

- The bus is transferred at a break between bus cycles. However, if a bus cycle is executed in
 discrete operations, as in the case of a longword-size access, the bus is not transferred between
 the operations. See Appendix A-5, Bus States During Instruction Execution, for timings at
 which the bus is not transferred.
- If the CPU is in sleep mode, it transfers the bus immediately.

DTC: The DTC sends the bus arbiter a request for the bus when an activation request is generated.

The DTC can release the bus after a vector read, a register information read (3 states), a single data transfer, or a register information write (3 states). It does not release the bus during a register information read (3 states), a single data transfer, or a register information write (3 states).

DMAC: The DMAC sends the bus arbiter a request for the bus when an activation request is generated.

In the case of an external request in short address mode or normal mode, and in cycle steal mode, the DMAC releases the bus after a single transfer.

In block transfer mode, it releases the bus after transfer of one block, and in burst mode, after completion of a transfer.

6.11.4 External Bus Release Usage Note

External bus release can be performed on completion of an external bus cycle. The \overline{RD} signal, DRAM interface \overline{RAS} and \overline{CAS} signals remain low until the end of the external bus cycle. Therefore, when external bus release is performed, the \overline{RD} , \overline{RAS} , and \overline{CAS} signals may change from the low level to the high-impedance state.

6.12 Resets and the Bus Controller

In a power-on reset, the H8S/2357 Series, including the bus controller, enters the reset state at that point, and an executing bus cycle is discontinued.

In a manual reset*, the bus controller's registers and internal state are maintained, and an executing external bus cycle is completed. In this case, \overline{WAIT} input is ignored. Also, since the DMAC is initialized by a manual reset*, \overline{DACK} and \overline{TEND} output is disabled and these pins become I/O ports controlled by DDR and DR.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Section 7 DMA Controller

7.1 Overview

The H8S/2357 Series has a built-in DMA controller (DMAC) which can carry out data transfer on up to 4 channels.

7.1.1 Features

The features of the DMAC are listed below.

- Choice of short address mode or full address mode
 - Short address mode
 - Maximum of 4 channels can be used
 - Choice of dual address mode or single address mode
 - In dual address mode, one of the two addresses, transfer source and transfer destination, is specified as 24 bits and the other as 16 bits
 - In single address mode, transfer source or transfer destination address only is specified as 24 bits
 - In single address mode, transfer can be performed in one bus cycle
 - Choice of sequential mode, idle mode, or repeat mode for dual address mode and single address mode

Full address mode

- Maximum of 2 channels can be used
- Transfer source and transfer destination address specified as 24 bits
- Choice of normal mode or block transfer mode
- 16-Mbyte address space can be specified directly
- Byte or word can be set as the transfer unit
- Activation sources: internal interrupt, external request, auto-request (depending on transfer mode)
 - Six 16-bit timer-pulse unit (TPU) compare match/input capture interrupts
 - Serial communication interface (SCI0, SCI1) transmission data empty interrupt, reception data full interrupt
 - A/D converter conversion end interrupt
 - External request
 - Auto-request

- Module stop mode can be set
 - The initial setting enables DMAC registers to be accessed. DMAC operation is halted by setting module stop mode

7.1.2 Block Diagram

A block diagram of the DMAC is shown in figure 7-1.

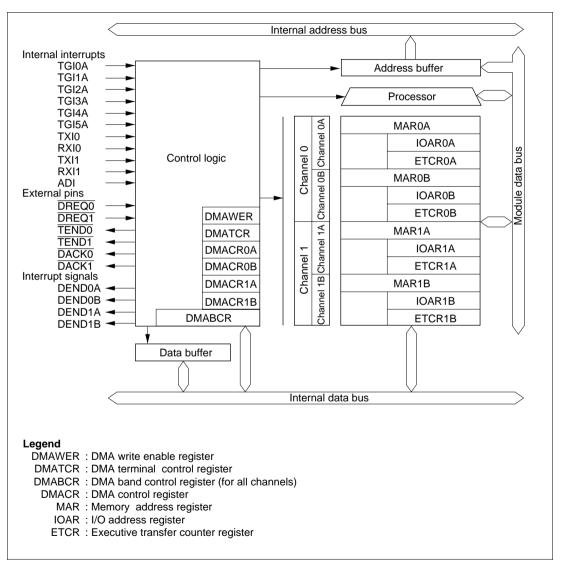


Figure 7-1 Block Diagram of DMAC

7.1.3 Overview of Functions

Tables 7-1 (1) and (2) summarize DMAC functions in short address mode and full address mode, respectively.

Table 7-1 (1) Overview of DMAC Functions (Short Address Mode)

				Address Register Bit Length				
Tr	ansfer Mode	Tr	ansfer Source	Source	Destination			
•	Sequential mode — 1-byte or 1-word transfer executed for one transfer request — Memory address incremented/decremented by 1 or 2 — 1 to 65536 transfers Idle mode — 1-byte or 1-word transfer executed for one transfer request — Memory address fixed — 1 to 65536 transfers Repeat mode — 1-byte or 1-word transfer executed for one transfer request — Repeat mode — 1-byte or 1-word transfer executed for one transfer request — Memory address incremented/decremented by 1 or 2 — After specified number of transfers (1 to 256), initial state is restored and operation continues	•	TPU channel 0 to 5 compare match/input capture A interrupt SCI transmission data empty interrupt SCI reception data full interrupt A/D converter conversion end interrupt External request	24/16	16/24			
• •	ngle address mode 1-byte or 1-word transfer executed for one transfer request Transfer in 1 bus cycle using DACK pin in place of address specifying I/O Specifiable for sequential, idle, and repeat modes	•	External request	24/DACK	DACK/24			

Table 7-1 (2) Overview of DMAC Functions (Full Address Mode)

				Address Register Bit Length					
Tr	ansfer Mode	Tr	ansfer Source	Source	Destination				
•	Normal mode Auto-request — Transfer request retained internally — Transfers continue for the specified number of times (1 to 65536) — Choice of burst or cycle steal transfer	•	Auto-request	24	24				
	 External request 1-byte or 1-word transfer executed for one transfer request 1 to 65536 transfers 	•	External request						
•	Block transfer mode Specified block size transfer executed for one transfer request 1 to 65536 transfers Either source or destination specifiable as block area Block size: 1 to 256 bytes or words	•	TPU channel 0 to 5 compare match/input capture A interrupt SCI transmission data empty interrupt SCI reception data full interrupt External request A/D converter conversion end interrupt	24	24				

7.1.4 Pin Configuration

Table 7-2 summarizes the DMAC pins.

In short address mode, external request transfer, single address transfer, and transfer end output are not performed for channel A.

The DMA transfer acknowledge function is used in channel B single address mode in short address mode.

When the \overline{DREQ} pin is used, do not designate the corresponding port for output.

With regard to the \overline{DACK} pins, setting single address transfer automatically sets the corresponding port to output, functioning as a \overline{DACK} pin.

With regard to the $\overline{\text{TEND}}$ pins, whether or not the corresponding port is used as a $\overline{\text{TEND}}$ pin can be specified by means of a register setting.

Table 7-2 DMAC Pins

Channel	Pin Name	Symbol	I/O	Function
0	DMA request 0	DREQ0	Input	DMAC channel 0 external request
	DMA transfer acknowledge 0	DACK0	Output	DMAC channel 0 single address transfer acknowledge
	DMA transfer end 0	TEND0	Output	DMAC channel 0 transfer end
1	DMA request 1	DREQ1	Input	DMAC channel 1 external request
	DMA transfer acknowledge 1	DACK1	Output	DMAC channel 1 single address transfer acknowledge
	DMA transfer end 1	TEND1	Output	DMAC channel 1 transfer end

7.1.5 Register Configuration

Table 7-3 summarizes the DMAC registers.

Table 7-3 DMAC Registers

Channel	Name	Abbreviation	R/W	Initial Value	Address*	Bus Width
0	Memory address register 0A	MAR0A	R/W	Undefined	H'FEE0	16 bits
	I/O address register 0A	IOAR0A	R/W	Undefined	H'FEE4	16 bits
	Transfer count register 0A	ETCR0A	R/W	Undefined	H'FEE6	16 bits
	Memory address register 0B	MAR0B	R/W	Undefined	H'FEE8	16 bits
	I/O address register 0B	IOAR0B	R/W	Undefined	H'FEEC	16 bits
	Transfer count register 0B	ETCR0B	R/W	Undefined	H'FEEE	16 bits
1	Memory address register 1A	MAR1A	R/W	Undefined	H'FEF0	16 bits
	I/O address register 1A	IOAR1A	R/W	Undefined	H'FEF4	16 bits
	Transfer count register 1A	ETCR1A	R/W	Undefined	H'FEF6	16 bits
	Memory address register 1B	MAR1B	R/W	Undefined	H'FEF8	16 bits
	I/O address register 1B	IOAR1B	R/W	Undefined	H'FEFC	16 bits
	Transfer count register 1B	ETCR1B	R/W	Undefined	H'FEFE	16 bits
0, 1	DMA write enable register	DMAWER	R/W	H'00	H'FF00	8 bits
	DMA terminal control register	DMATCR	R/W	H'00	H'FF01	8 bits
	DMA control register 0A	DMACR0A	R/W	H'00	H'FF02	16 bits
	DMA control register 0B	DMACR0B	R/W	H'00	H'FF03	16 bits
	DMA control register 1A	DMACR1A	R/W	H'00	H'FF04	16 bits
	DMA control register 1B	DMACR1B	R/W	H'00	H'FF05	16 bits
	DMA band control register	DMABCR	R/W	H'0000	H'FF06	16 bits
	Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C	8 bits

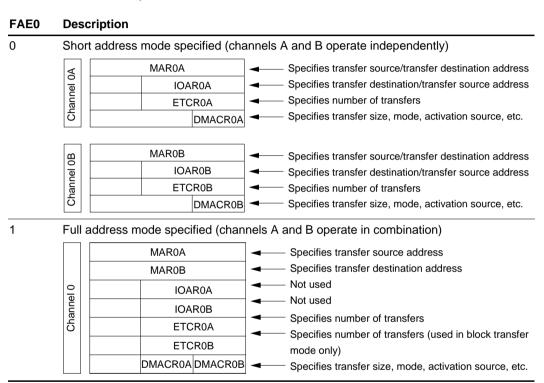
Note: * Lower 16 bits of the address.

7.2 Register Descriptions (1) (Short Address Mode)

Short address mode transfer can be performed for channels A and B independently.

Short address mode transfer is specified for each channel by clearing the FAE bit in DMABCR to 0, as shown in table 7-4. Short address mode or full address mode can be selected for channels 1 and 0 independently by means of bits FAE1 and FAE0.

Table 7-4 Short Address Mode and Full Address Mode (For 1 Channel: Example of Channel 0)



7.2.1 Memory Address Registers (MAR)

Bit :	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
MAR :	_	_	_	_	_	_	_	_								
Initial value:	0	0	0	0	0	0	0	0	*	*	*	*	*	*	*	*
R/W :	_	_	_	_	_	_	_	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
MAR :																
Initial value:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

*: Undefined

MAR is a 32-bit readable/writable register that specifies the transfer source address or destination address.

The upper 8 bits of MAR are reserved: they are always read as 0, and cannot be modified.

Whether MAR functions as the source address register or as the destination address register can be selected by means of the DTDIR bit in DMACR.

MAR is incremented or decremented each time a byte or word transfer is executed, so that the address specified by MAR is constantly updated. For details, see section 7.2.4, DMA Control Register (DMACR).

MAR is not initialized by a reset or in standby mode.

7.2.2 I/O Address Register (IOAR)

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
IOAR	:																
Initial value		*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*

*: Undefined

IOAR is a 16-bit readable/writable register that specifies the lower 16 bits of the transfer source address or destination address. The upper 8 bits of the transfer address are automatically set to H'FF.

Whether IOAR functions as the source address register or as the destination address register can be selected by means of the DTDIR bit in DMACR.

IOAR is invalid in single address mode.

IOAR is not incremented or decremented each time a transfer is executed, so that the address specified by IOAR is fixed.

IOAR is not initialized by a reset or in standby mode.

7.2.3 Execute Transfer Count Register (ETCR)

ETCR is a 16-bit readable/writable register that specifies the number of transfers. The setting of this register is different for sequential mode and idle mode on the one hand, and for repeat mode on the other.

(1) Sequential Mode and Idle Mode

Transfer Counter

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
ETCR	:																
Initial value	٠.	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*

 $\mathsf{R/W} \qquad : \ \mathsf{R/W}$

*: Undefined

In sequential mode and idle mode, ETCR functions as a 16-bit transfer counter (with a count range of 1 to 65536). ETCR is decremented by 1 each time a transfer is performed, and when the count reaches H'0000, the DTE bit in DMABCR is cleared, and transfer ends.

(2) Repeat Mode

Transfer Number Storage

Bit	:	15	14	13	12	11	10	9	8
ETCRH	:								
Initial valu	ie:	*	*	*	*	*	*	*	*
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Transfer	Cour	nter							
Bit	: _	7	6	5	4	3	2	1	0
ETCRL	:								
Initial valu	ie:	*	*	*	*	*	*	*	*

*: Undefined

In repeat mode, ETCR functions as transfer counter ETCRL (with a count range of 1 to 256) and transfer number storage register ETCRH. ETCRL is decremented by 1 each time a transfer is performed, and when the count reaches H'00, ETCRL is loaded with the value in ETCRH. At this point, MAR is automatically restored to the value it had when the count was started. The DTE bit in DMABCR is not cleared, and so transfers can be performed repeatedly until the DTE bit is cleared by the user.

ETCR is not initialized by a reset or in standby mode.

7.2.4 DMA Control Register (DMACR)

Bit	:	7	6	5	4	3	2	1	0
DMACR	:	DTSZ	DTID5	RPE	DTDIR	DTF3	DTF2	DTF1	DTF0
Initial val	ue:	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DMACR is an 8-bit readable/writable register that controls the operation of each DMAC channel.

DMACR is initialized to H'00 by a reset, and in hardware standby mode.

Bit 7—Data Transfer Size (DTSZ): Selects the size of data to be transferred at one time.

Bit 7 DTSZ	Description	
0	Byte-size transfer	(Initial value)
1	Word-size transfer	

Bit 6—Data Transfer Increment/Decrement (DTID): Selects incrementing or decrementing of MAR every data transfer in sequential mode or repeat mode.

In idle mode, MAR is neither incremented nor decremented.

Bit 6 DTID	Description	
0	MAR is incremented after a data transfer	(Initial value)
	 When DTSZ = 0, MAR is incremented by 1 after a transfer 	
	 When DTSZ = 1, MAR is incremented by 2 after a transfer 	
1	MAR is decremented after a data transfer	
	 When DTSZ = 0, MAR is decremented by 1 after a transfer 	
	 When DTSZ = 1, MAR is decremented by 2 after a transfer 	

Bit 5—Repeat Enable (RPE): Used in combination with the DTIE bit in DMABCR to select the mode (sequential, idle, or repeat) in which transfer is to be performed.

Bit 5 RPE	DMABCR DTIE	Description	
0	0	Transfer in sequential mode (no transfer end interrupt)	(Initial value)
	1	Transfer in sequential mode (with transfer end interrupt)	
1	0	Transfer in repeat mode (no transfer end interrupt)	
	1	Transfer in idle mode (with transfer end interrupt)	

For details of operation in sequential, idle, and repeat mode, see section 7.5.2, Sequential Mode, section 7.5.3, Idle Mode, and section 7.5.4, Repeat Mode.

Bit 4—Data Transfer Direction (DTDIR): Used in combination with the SAE bit in DMABCR to specify the data transfer direction (source or destination). The function of this bit is therefore different in dual address mode and single address mode.

DMABCR SAE	Bit 4 DTDIR	Description
0	0	Transfer with MAR as source address and IOAR as destination address (Initial value)
	1	Transfer with IOAR as source address and MAR as destination address
1	0	Transfer with MAR as source address and DACK pin as write strobe
	1	Transfer with DACK pin as read strobe and MAR as destination address

Bits 3 to 0—Data Transfer Factor (DTF3 to DTF0): These bits select the data transfer factor (activation source). There are some differences in activation sources for channel A and for channel B.

Channel A

Bit 3 DTF3	Bit 2 DTF2	Bit 1 DTF1	Bit 0 DTF0	Description
0	0	0	0	— (Initial value)
			1	Activated by A/D converter conversion end interrupt
		1	0	_
			1	_
	1	0	0	Activated by SCI channel 0 transmission data empty interrupt
			1	Activated by SCI channel 0 reception data full interrupt
		1	0	Activated by SCI channel 1 transmission data empty interrupt
			1	Activated by SCI channel 1 reception data full interrupt
1			0	Activated by TPU channel 0 compare match/input capture A interrupt
			1	Activated by TPU channel 1 compare match/input capture A interrupt
		1	0	Activated by TPU channel 2 compare match/input capture A interrupt
			1	Activated by TPU channel 3 compare match/input capture A interrupt
	1	0	0	Activated by TPU channel 4 compare match/input capture A interrupt
			1	Activated by TPU channel 5 compare match/input capture A interrupt
		1	0	_
			1	_

Channel B

Bit 3 DTF3	Bit 2 DTF2	Bit 1 DTF1	Bit 0 DTF0	Description
0	0	0	0	— (Initial value)
			1	Activated by A/D converter conversion end interrupt
		1	0	Activated by DREQ pin falling edge input*
			1	Activated by DREQ pin low-level input
	1	0	0	Activated by SCI channel 0 transmission data empty interrupt
			1	Activated by SCI channel 0 reception data full interrupt
		1	0	Activated by SCI channel 1 transmission data empty interrupt
			1	Activated by SCI channel 1 reception data full interrupt
1	0	0 0 0 Activated by A interrupt		Activated by TPU channel 0 compare match/input capture A interrupt
			1	Activated by TPU channel 1 compare match/input capture A interrupt
		1	0	Activated by TPU channel 2 compare match/input capture A interrupt
			1	Activated by TPU channel 3 compare match/input capture A interrupt
	1	0	0	Activated by TPU channel 4 compare match/input capture A interrupt
			1	Activated by TPU channel 5 compare match/input capture A interrupt
		1	0	_
			1	_

Note: * Detected as a low level in the first transfer after transfer is enabled.

The same factor can be selected for more than one channel. In this case, activation starts with the highest-priority channel according to the relative channel priorities. For relative channel priorities, see section 7.5.13, DMAC Multi-Channel Operation.

7.2.5 DMA Band Control Register (DMABCR)

Bit :	15	14	13	12	11	10	9	8
DMABCRH:	FAE1	FAE0	SAE1	SAE0	DTA1B	DTA1A	DTA0B	DTA0A
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit :	7	6	5	4	3	2	1	0
DMABCRL:	DTE1B	DTE1A	DTE0B	DTE0A	DTIE1B	DTIE1A	DTIE0B	DTIE0A
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DMABCR is a 16-bit readable/writable register that controls the operation of each DMAC channel.

DMABCR is initialized to H'0000 by a reset, and in hardware standby mode.

Bit 15—Full Address Enable 1 (FAE1): Specifies whether channel 1 is to be used in short address mode or full address mode.

In short address mode, channels 1A and 1B are used as independent channels.

Bit 15 FAE1	Description	
0	Short address mode	(Initial value)
1	Full address mode	

Bit 14—Full Address Enable 0 (FAE0): Specifies whether channel 0 is to be used in short address mode or full address mode.

In short address mode, channels 0A and 0B are used as independent channels.

Bit 14		
FAE0	Description	
0	Short address mode	(Initial value)
1	Full address mode	

Bit 13—Single Address Enable 1 (SAE1): Specifies whether channel 1B is to be used for transfer in dual address mode or single address mode.

Bit 13		
SAE1	Description	
0	Transfer in dual address mode	(Initial value)
1	Transfer in single address mode	

This bit is invalid in full address mode.

Bit 12—Single Address Enable 0 (SAE0): Specifies whether channel 0B is to be used for transfer in dual address mode or single address mode.

Bit 12 SAE0	Description	
0	Transfer in dual address mode	(Initial value)
1	Transfer in single address mode	

This bit is invalid in full address mode.

Bits 11 to 8—Data Transfer Acknowledge (DTA): These bits enable or disable clearing, when DMA transfer is performed, of the internal interrupt source selected by the data transfer factor setting.

When DTE = 1 and DTA = 1, the internal interrupt source selected by the data transfer factor setting is cleared automatically by DMA transfer. When DTE = 1 and DTA = 1, the internal interrupt source selected by the data transfer factor setting does not issue an interrupt request to the CPU or DTC.

When DTE = 1 and DTA = 0, the internal interrupt source selected by the data transfer factor setting is not cleared when a transfer is performed, and can issue an interrupt request to the CPU or DTC in parallel. In this case, the interrupt source should be cleared by the CPU or DTC transfer.

When DTE = 0, the internal interrupt source selected by the data transfer factor setting issues an interrupt request to the CPU or DTC regardless of the DTA bit setting.

Bit 11—Data Transfer Acknowledge 1B (DTA1B): Enables or disables clearing, when DMA transfer is performed, of the internal interrupt source selected by the channel 1B data transfer factor setting.

Bit 11 DTA1B	Description
0	Clearing of selected internal interrupt source at time of DMA transfer is disabled (Initial value)
1	Clearing of selected internal interrupt source at time of DMA transfer is enabled

Bit 10—Data Transfer Acknowledge 1A (DTA1A): Enables or disables clearing, when DMA transfer is performed, of the internal interrupt source selected by the channel 1A data transfer factor setting.

Bit 10 DTA1A	Description
0	Clearing of selected internal interrupt source at time of DMA transfer is disabled (Initial value)
1	Clearing of selected internal interrupt source at time of DMA transfer is enabled

Bit 9—Data Transfer Acknowledge 0B (DTA0B): Enables or disables clearing, when DMA transfer is performed, of the internal interrupt source selected by the channel 0B data transfer factor setting.

Bit 9 DTA0B	Description
0	Clearing of selected internal interrupt source at time of DMA transfer is disabled (Initial value)
1	Clearing of selected internal interrupt source at time of DMA transfer is enabled

Bit 8—Data Transfer Acknowledge 0A (DTA0A): Enables or disables clearing, when DMA transfer is performed, of the internal interrupt source selected by the channel 0A data transfer factor setting.

Bit 8 DTA0A	Description
0	Clearing of selected internal interrupt source at time of DMA transfer is disabled (Initial value)
1	Clearing of selected internal interrupt source at time of DMA transfer is enabled

Bits 7 to 4—Data Transfer Enable (DTE): When DTE = 0, data transfer is disabled and the activation source selected by the data transfer factor setting is ignored. If the activation source is an internal interrupt, an interrupt request is issued to the CPU or DTC. If the DTIE bit is set to 1 when DTE = 0, the DMAC regards this as indicating the end of a transfer, and issues a transfer end interrupt request to the CPU or DTC.

The conditions for the DTE bit being cleared to 0 are as follows:

- When initialization is performed
- When the specified number of transfers have been completed in a transfer mode other than repeat mode
- When 0 is written to the DTE bit to forcibly abort the transfer, or for a similar reason

When DTE = 1, data transfer is enabled and the DMAC waits for a request by the activation source selected by the data transfer factor setting. When a request is issued by the activation source, DMA transfer is executed.

The condition for the DTE bit being set to 1 is as follows:

• When 1 is written to the DTE bit after the DTE bit is read as 0.

Bit 7—Data Transfer Enable 1B (DTE1B): Enables or disables data transfer on channel 1B.

Bit 7		
DTE1B	Description	
0	Data transfer disabled	(Initial value)
1	Data transfer enabled	

Bit 6—Data Transfer Enable 1A (DTE1A): Enables or disables data transfer on channel 1A.

Bit 6		
DTE1A	Description	
0	Data transfer disabled	(Initial value)
1	Data transfer enabled	

Bit 5—Data Transfer Enable 0B (DTE0B): Enables or disables data transfer on channel 0B.

Bit 5 DTE0B	Description	
0	Data transfer disabled	(Initial value)
1	Data transfer enabled	

Bit 4—Data Transfer Enable 0A (DTE0A): Enables or disables data transfer on channel 0A.

Bit 4 DTE0A	Description					
	Data transfer disabled	(Initial value)				
1	Data transfer enabled					

Bits 3 to 0—Data Transfer End Interrupt Enable (DTIE): These bits enable or disable an interrupt to the CPU or DTC when transfer ends. If the DTIE bit is set to 1 when DTE = 0, the DMAC regards this as indicating the end of a transfer, and issues a transfer end interrupt request to the CPU or DTC.

A transfer end interrupt can be canceled either by clearing the DTIE bit to 0 in the interrupt handling routine, or by performing processing to continue transfer by setting the transfer counter and address register again, and then setting the DTE bit to 1.

Bit 3—Data Transfer Interrupt Enable 1B (DTIE1B): Enables or disables the channel 1B transfer end interrupt.

Bit 3		
DTIE1B	Description	
0	Transfer end interrupt disabled	(Initial value)
1	Transfer end interrupt enabled	

Bit 2—Data Transfer Interrupt Enable 1A (DTIE1A): Enables or disables the channel 1A transfer end interrupt.

Bit 2 DTIE1A	Description	
0	Transfer end interrupt disabled	(Initial value)
1	Transfer end interrupt enabled	

Bit 1—Data Transfer Interrupt Enable 0B (DTIE0B): Enables or disables the channel 0B transfer end interrupt.

Bit 1		
DTIE0B	Description	
0	Transfer end interrupt disabled	(Initial value)
1	Transfer end interrupt enabled	

Bit 0—Data Transfer Interrupt Enable 0A (DTIE0A): Enables or disables the channel 0A transfer end interrupt.

Bit 0 DTIE0A	Description	
0	Transfer end interrupt disabled	(Initial value)
1	Transfer end interrupt enabled	

7.3 Register Descriptions (2) (Full Address Mode)

Full address mode transfer is performed with channels A and B together. For details of full address mode setting, see table 7-4.

7.3.1 Memory Address Register (MAR)

Bit	:	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
MAR	:		_	_	_	_	_	_	_								
Initial value	e :	0	0	0	0	0	0	0	0	*	*	*	*	*	*	*	*
R/W	:	_	_	_	_	_	_	_	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
MAR	:																
Initial value	e :	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
R/W		R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

*: Undefined

MAR is a 32-bit readable/writable register; MARA functions as the transfer source address register, and MARB as the destination address register.

MAR is composed of two 16-bit registers, MARH and MARL. The upper 8 bits of MARH are reserved: they are always read as 0, and cannot be modified.

MAR is incremented or decremented each time a byte or word transfer is executed, so that the source or destination memory address can be updated automatically. For details, see section 7.3.4, DMA Control Register (DMACR).

MAR is not initialized by a reset or in standby mode.

7.3.2 I/O Address Register (IOAR)

IOAR is not used in full address transfer.

7.3.3 Execute Transfer Count Register (ETCR)

ETCR is a 16-bit readable/writable register that specifies the number of transfers. The function of this register is different in normal mode and in block transfer mode.

ETCR is not initialized by a reset or in standby mode.

(1) Normal Mode

ETCRA

_		_	
Tran	ofor	Counter	
Han	Siei	Counter	

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
ETCR	:																
Initial value	٠.	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*

*: Undefined

In normal mode, ETCRA functions as a 16-bit transfer counter. ETCRA is decremented by 1 each time a transfer is performed, and transfer ends when the count reaches H'0000. ETCRB is not used at this time.

ETCRB

ETCRB is not used in normal mode.

(2) Block Transfer Mode

ETCRA

Holds	bloc	k size
-------	------	--------

Bit	:	15	14	13	12	11	10	9	8				
ETCRAH	:												
Initial valu	e:	*	*	*	*	*	*	*	*				
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W				
Block size	Block size counter												
Bit	:	7	6	5	4	3	2	1	0				
Bit ETCRAL	: :[7	6	5	4	3	2	1	0				
	:[*	*	*	*	*	*	*	*				

*: Undefined

Block Transfer Counter

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
ETCRB	:																	ı
Initial value	e :	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	

In block transfer mode, ETCRAL functions as an 8-bit block size counter and ETCRAH holds the block size. ETCRAL is decremented each time a 1-byte or 1-word transfer is performed, and when the count reaches H'00, ETCRAL is loaded with the value in ETCRAH. So by setting the block size in ETCRAH and ETCRAL, it is possible to repeatedly transfer blocks consisting of any desired number of bytes or words.

ETCRB functions in block transfer mode, as a 16-bit block transfer counter. ETCRB is decremented by 1 each time a block is transferred, and transfer ends when the count reaches H'0000.

7.3.4 DMA Control Register (DMACR)

DMACR is a 16-bit readable/writable register that controls the operation of each DMAC channel. In full address mode, DMACRA and DMACRB have different functions.

DMACR is initialized to H'0000 by a reset, and in hardware standby mode.

DMACRA

Bit :	15	14	13	12	11	10	9	8
DMACRA :	DTSZ	SAID	SAIDE	BLKDIR	BLKE			_
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DMACRB

Bit	:	7	6	5	4	3	2	1	0
DMACRB	:	_	DAID	DAIDE	_	DTF3	DTF2	DTF1	DTF0
Initial value	:	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Bit 15—Data Transfer Size (DTSZ): Selects the size of data to be transferred at one time.

Bit 15 DTSZ	Description	
0	Byte-size transfer	(Initial value)
1	Word-size transfer	

Bit 14—Source Address Increment/Decrement (SAID)

Bit 13—Source Address Increment/Decrement Enable (SAIDE): These bits specify whether source address register MARA is to be incremented, decremented, or left unchanged, when data transfer is performed.

Bit 14 SAID	Bit 13 SAIDE	Description	
0	0	MARA is fixed	(Initial value)
	1	MARA is incremented after a data transfer	
		• When DTSZ = 0, MARA is incremented by 1 after a tran	sfer
		• When DTSZ = 1, MARA is incremented by 2 after a tran	sfer
1	0	MARA is fixed	
	1	MARA is decremented after a data transfer	
		• When DTSZ = 0, MARA is decremented by 1 after a tran	nsfer
		• When DTSZ = 1, MARA is decremented by 2 after a train	nsfer

Bit 12—Block Direction (BLKDIR)

Bit 11—Block Enable (BLKE): These bits specify whether normal mode or block transfer mode is to be used. If block transfer mode is specified, the BLKDIR bit specifies whether the source side or the destination side is to be the block area.

Bit 12 BLKDIR	Bit 11 BLKE	Description	
0	0	Transfer in normal mode	(Initial value)
	1	Transfer in block transfer mode, destination side is block ar	ea
1	0	Transfer in normal mode	
	1	Transfer in block transfer mode, source side is block area	

For operation in normal mode and block transfer mode, see section 7.5, Operation.

Bits 10 to 7—Reserved: Can be read or written to.

Bit 6—Destination Address Increment/Decrement (DAID)

Bit 5—Destination Address Increment/Decrement Enable (DAIDE): These bits specify whether destination address register MARB is to be incremented, decremented, or left unchanged, when data transfer is performed.

Bit 6 DAID	Bit 5 DAIDE	Description	
0	0	MARB is fixed (Ini	itial value)
	1	MARB is incremented after a data transfer	
		• When DTSZ = 0, MARB is incremented by 1 after a transfer	
		• When DTSZ = 1, MARB is incremented by 2 after a transfer	
1	0	MARB is fixed	
	1	MARB is decremented after a data transfer	
		• When DTSZ = 0, MARB is decremented by 1 after a transfer	
		• When DTSZ = 1, MARB is decremented by 2 after a transfer	

Bit 4—Reserved: Can be read or written to.

Bits 3 to 0—Data Transfer Factor (DTF3 to DTF0): These bits select the data transfer factor (activation source). The factors that can be specified differ between normal mode and block transfer mode.

Normal Mode

Bit 3 DTF3	Bit 2 DTF2	Bit 1 DTF1	Bit 0 DTF0	Description	
0	0	0	0	_	(Initial value)
			1	_	
		1	0	Activated by DREQ pin falling edge input	
			1	Activated by DREQ pin low-level input	
	1	0	*	_	
		1	0	Auto-request (cycle steal)	
			1	Auto-request (burst)	
1	*	*	*	_	

*: Don't care

Block Transfer Mode

Bit 3 DTF3	Bit 2 DTF2	Bit 1 DTF1	Bit 0 DTF0	Description	
0	0	0	0	— (Initial value)	
			1	Activated by A/D converter conversion end interrupt	
		1	0	Activated by DREQ pin falling edge input*	
			1	Activated by DREQ pin low-level input	
	1	0	0	Activated by SCI channel 0 transmission data empty interrupt	
			1	Activated by SCI channel 0 reception data full interrupt	
		1	0	Activated by SCI channel 1 transmission data empty interrupt	
			1	Activated by SCI channel 1 reception data full interrupt	
1	0	0	0	Activated by TPU channel 0 compare match/input capture A interrupt	
			1	Activated by TPU channel 1 compare match/input capture A interrupt	
		1	0	Activated by TPU channel 2 compare match/input capture A interrupt	
					1
	1	0	0	Activated by TPU channel 4 compare match/input capture A interrupt	
			1	Activated by TPU channel 5 compare match/input capture A interrupt	
		1	0	_	
			1	_	

Note: * Detected as a low level in the first transfer after transfer is enabled.

The same factor can be selected for more than one channel. In this case, activation starts with the highest-priority channel according to the relative channel priorities. For relative channel priorities, see section 7.5.13, DMAC Multi-Channel Operation.

7.3.5 DMA Band Control Register (DMABCR)

Bit :	15	14	13	12	11	10	9	8
DMABCRH:	FAE1	FAE0	_	_	DTA1	_	DTA0	_
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit :	7	6	5	4	3	2	1	0
DMABCRL:	DTME1	DTE1	DTME0	DTE0	DTIE1B	DTIE1A	DTIE0B	DTIE0A
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DMABCR is a 16-bit readable/writable register that controls the operation of each DMAC channel.

DMABCR is initialized to H'0000 by a reset, and in standby mode.

Bit 15—Full Address Enable 1 (FAE1): Specifies whether channel 1 is to be used in short address mode or full address mode.

In full address mode, channels 1A and 1B are used together as a single channel.

Bit 15 FAE1	Description	
0	Short address mode	(Initial value)
1	Full address mode	

Bit 14—Full Address Enable 0 (FAE0): Specifies whether channel 0 is to be used in short address mode or full address mode.

In full address mode, channels 0A and 0B are used together as a single channel.

Bit 14		
FAE0	Description	
0	Short address mode	(Initial value)
1	Full address mode	

Bits 13 and 12—Reserved: Can be read or written to.

Bits 11 and 9—Data Transfer Acknowledge (DTA): These bits enable or disable clearing, when DMA transfer is performed, of the internal interrupt source selected by the data transfer factor setting.

When DTE = 1 and DTA = 1, the internal interrupt source selected by the data transfer factor setting is cleared automatically by DMA transfer. When DTE = 1 and DTA = 1, the internal interrupt source selected by the data transfer factor setting does not issue an interrupt request to the CPU or DTC.

When the DTE = 1 and the DTA = 0, the internal interrupt source selected by the data transfer factor setting is not cleared when a transfer is performed, and can issue an interrupt request to the CPU or DTC in parallel. In this case, the interrupt source should be cleared by the CPU or DTC transfer.

When the DTE = 0, the internal interrupt source selected by the data transfer factor setting issues an interrupt request to the CPU or DTC regardless of the DTA bit setting.

The state of the DTME bit does not affect the above operations.

Bit 11—Data Transfer Acknowledge 1 (DTA1): Enables or disables clearing, when DMA transfer is performed, of the internal interrupt source selected by the channel 1 data transfer factor setting.

Bit 11 DTA1	Description
0	Clearing of selected internal interrupt source at time of DMA transfer is disabled (Initial value)
1	Clearing of selected internal interrupt source at time of DMA transfer is enabled

Bit 9—Data Transfer Acknowledge 0 (DTA0): Enables or disables clearing, when DMA transfer is performed, of the internal interrupt source selected by the channel 0 data transfer factor setting.

Bit 9 DTA0	Description
0	Clearing of selected internal interrupt source at time of DMA transfer is disabled (Initial value)
1	Clearing of selected internal interrupt source at time of DMA transfer is enabled

Bits 10 and 8—Reserved: Can be read or written to.

Bits 7 and 5—Data Transfer Master Enable (DTME): Together with the DTE bit, these bits control enabling or disabling of data transfer on the relevant channel. When both the DTME bit and the DTE bit are set to 1, transfer is enabled for the channel.

If the relevant channel is in the middle of a burst mode transfer when an NMI interrupt is generated, the DTME bit is cleared, the transfer is interrupted, and bus mastership passes to the CPU. When the DTME bit is subsequently set to 1 again, the interrupted transfer is resumed. In block transfer mode, however, the DTME bit is not cleared by an NMI interrupt, and transfer is not interrupted.

The conditions for the DTME bit being cleared to 0 are as follows:

- When initialization is performed
- When NMI is input in burst mode
- When 0 is written to the DTME bit

The condition for DTME being set to 1 is as follows:

• When 1 is written to DTME after DTME is read as 0

Bit 7—Data Transfer Master Enable 1 (DTME1): Enables or disables data transfer on channel 1.

Bit 7 DTME1	Description	
0	Data transfer disabled. In burst mode, cleared to 0 by an NMI interrupt	(Initial value)
1	Data transfer enabled	

Bit 5—Data Transfer Master Enable 0 (DTME0): Enables or disables data transfer on channel 0.

Bit 5		
DTME0	Description	
0	Data transfer disabled. In normal mode, cleared to 0 by an NMI interrupt	(Initial value)
1	Data transfer enabled	

Bits 6 and 4—Data Transfer Enable (DTE): When DTE = 0, data transfer is disabled and the activation source selected by the data transfer factor setting is ignored. If the activation source is an internal interrupt, an interrupt request is issued to the CPU or DTC. If the DTIE bit is set to 1 when DTE = 0, the DMAC regards this as indicating the end of a transfer, and issues a transfer end interrupt request to the CPU.

The conditions for the DTE bit being cleared to 0 are as follows:

- When initialization is performed
- When the specified number of transfers have been completed
- When 0 is written to the DTE bit to forcibly abort the transfer, or for a similar reason

When DTE = 1 and DTME = 1, data transfer is enabled and the DMAC waits for a request by the activation source selected by the data transfer factor setting. When a request is issued by the activation source, DMA transfer is executed.

The condition for the DTE bit being set to 1 is as follows:

• When 1 is written to the DTE bit after the DTE bit is read as 0

Bit 6—Data Transfer Enable 1 (DTE1): Enables or disables data transfer on channel 1.

Bit 6		
DTE1	Description	
0	Data transfer disabled	(Initial value)
1	Data transfer enabled	

Bit 4—Data Transfer Enable 0 (DTE0): Enables or disables data transfer on channel 0.

Bit 4		
DTE0	Description	
0	Data transfer disabled	(Initial value)
1	Data transfer enabled	

Bits 3 and 1—Data Transfer Interrupt Enable B (DTIEB): These bits enable or disable an interrupt to the CPU or DTC when transfer is interrupted. If the DTIEB bit is set to 1 when DTME = 0, the DMAC regards this as indicating a break in the transfer, and issues a transfer break interrupt request to the CPU or DTC.

A transfer break interrupt can be canceled either by clearing the DTIEB bit to 0 in the interrupt handling routine, or by performing processing to continue transfer by setting the DTME bit to 1.

Bit 3—Data Transfer Interrupt Enable 1B (DTIE1B): Enables or disables the channel 1 transfer break interrupt.

Bit 3		
DTIE1B	Description	
0	Transfer break interrupt disabled	(Initial value)
1	Transfer break interrupt enabled	

Bit 1—Data Transfer Interrupt Enable 0B (DTIE0B): Enables or disables the channel 0 transfer break interrupt.

Bit 1		
DTIE0B	Description	
0	Transfer break interrupt disabled	(Initial value)
1	Transfer break interrupt enabled	

Bits 2 and 0—Data Transfer End Interrupt Enable A (DTIEA): These bits enable or disable an interrupt to the CPU or DTC when transfer ends. If DTIEA bit is set to 1 when DTE = 0, the DMAC regards this as indicating the end of a transfer, and issues a transfer end interrupt request to the CPU or DTC.

A transfer end interrupt can be canceled either by clearing the DTIEA bit to 0 in the interrupt handling routine, or by performing processing to continue transfer by setting the transfer counter and address register again, and then setting the DTE bit to 1.

Bit 2—Data Transfer Interrupt Enable 1A (DTIE1A): Enables or disables the channel 1 transfer end interrupt.

Bit 2 DTIE1A	Description	
0	Transfer end interrupt disabled	(Initial value)
1	Transfer end interrupt enabled	

Bit 0—Data Transfer Interrupt Enable 0A (DTIE0A): Enables or disables the channel 0 transfer end interrupt.

Bit 0		
DTIE0A	Description	
0	Transfer end interrupt disabled	(Initial value)
1	Transfer end interrupt enabled	

7.4 Register Descriptions (3)

7.4.1 DMA Write Enable Register (DMAWER)

The DMAC can activate the DTC with a transfer end interrupt, rewrite the channel on which the transfer ended using a DTC chain transfer, and reactivate the DTC. DMAWER applies restrictions so that specific bits of DMACR for the specific channel, and also DMATCR and DMABCR, can be changed to prevent inadvertent rewriting of registers other than those for the channel concerned. The restrictions applied by DMAWER are valid for the DTC.

Figure 7-2 shows the transfer areas for activating the DTC with a channel 0A transfer end interrupt, and reactivating channel 0A. The address register and count register area is re-set by the first DTC transfer, then the control register area is re-set by the second DTC chain transfer.

When re-setting the control register area, perform masking by setting bits in DMAWER to prevent modification of the contents of the other channels.

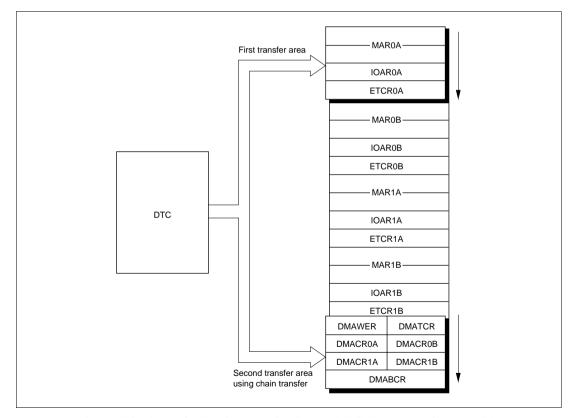


Figure 7-2 Areas for Register Re-Setting by DTC (Example: Channel 0A)

Bit :	7	6	5	4	3	2	1	0
DMAWER :	_	_	_	_	WE1B	WE1A	WE0B	WE0A
Initial value:	0	0	0	0	0	0	0	0
R/W :	_	_	_	_	R/W	R/W	R/W	R/W

DMAWER is an 8-bit readable/writable register that controls enabling or disabling of writes to the DMACR, DMABCR, and DMATCR by the DTC.

DMAWER is initialized to H'00 by a reset, and in standby mode.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—Write Enable 1B (WE1B): Enables or disables writes to all bits in DMACR1B, bits 11, 7, and 3 in DMABCR, and bit 5 in DMATCR by the DTC.

Bit 3 WE1B	Description
0	Writes to all bits in DMACR1B, bits 11, 7, and 3 in DMABCR, and bit 5 in DMATCR are disabled (Initial value)
1	Writes to all bits in DMACR1B, bits 11, 7, and 3 in DMABCR, and bit 5 in DMATCR are enabled

Bit 2—Write Enable 1A (WE1A): Enables or disables writes to all bits in DMACR1A, and bits 10, 6, and 2 in DMABCR by the DTC.

Bit 2 WE1A	Description
0	Writes to all bits in DMACR1A, and bits 10, 6, and 2 in DMABCR are disabled (Initial value)
1	Writes to all bits in DMACR1A, and bits 10, 6, and 2 in DMABCR are enabled

Bit 1—Write Enable 0B (WE0B): Enables or disables writes to all bits in DMACR0B, bits 9, 5, and 1 in DMABCR, and bit 4 in DMATCR.

Bit 1 WE0B	Description
0	Writes to all bits in DMACR0B, bits 9, 5, and 1 in DMABCR, and bit 4 in DMATCR are disabled (Initial value)
1	Writes to all bits in DMACR0B, bits 9, 5, and 1 in DMABCR, and bit 4 in DMATCR are enabled

Bit 0—Write Enable 0A (WE0A): Enables or disables writes to all bits in DMACR0A, and bits 8, 4, and 0 in DMABCR.

Bit 0 WE0A	Description
0	Writes to all bits in DMACR0A, and bits 8, 4, and 0 in DMABCR are disabled
	(Initial value)
1	Writes to all bits in DMACR0A, and bits 8, 4, and 0 in DMABCR are enabled

Writes by the DTC to bits 15 to 12 (FAE and SAE) in DMABCR are invalid regardless of the DMAWER settings. These bits should be changed, if necessary, by CPU processing.

In writes by the DTC to bits 7 to 4 (DTE) in DMABCR, 1 can be written without first reading 0. To reactivate a channel set to full address mode, write 1 to both Write Enable A and Write Enable B for the channel to be reactivated.

MAR, IOAR, and ETCR are always write-enabled regardless of the DMAWER settings. When modifying these registers, the channel for which the modification is to be made should be halted.

7.4.2 DMA Terminal Control Register (DMATCR)

Bit	:	7	6	5	4	3	2	1	0
DMATCR	:	_	_	TEE1	TEE0	_	_	_	_
Initial value	э:	0	0	0	0	0	0	0	0
R/W	:	_	_	R/W	R/W	_	_	_	_

DMATCR is an 8-bit readable/writable register that controls enabling or disabling of DMAC transfer end pin output. A port can be set for output automatically, and a transfer end signal output, by setting the appropriate bit.

DMATCR is initialized to H'00 by a reset, and in standby mode.

Bits 7 and 6—Reserved: These bits cannot be modified and are always read as 0.

Bit 5—Transfer End Enable 1 (TEE1): Enables or disables transfer end pin 1 (TEND1) output.

Bit 5		
TEE1	Description	
0	TEND1 pin output disabled	(Initial value)
1	TEND1 pin output enabled	

Bit 4—Transfer End Enable 0 (TEE0): Enables or disables transfer end pin 0 (TENDO) output.

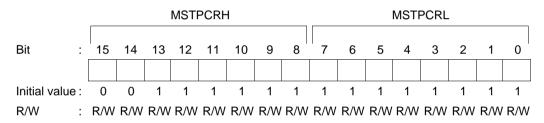
Bit 4		
TEE0	Description	
0	TEND0 pin output disabled	(Initial value)
1	TEND0 pin output enabled	

The TEND pins are assigned only to channel B in short address mode.

The transfer end signal indicates the transfer cycle in which the transfer counter reached 0, regardless of the transfer source. An exception is block transfer mode, in which the transfer end signal indicates the transfer cycle in which the block counter reached 0.

Bits 3 to 0—Reserved: These bits cannot be modified and are always read as 0.

7.4.3 Module Stop Control Register (MSTPCR)



MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP15 bit in MSTPCR is set to 1, the DMAC operation stops at the end of the bus cycle and a transition is made to module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 15—Module Stop (MSTP15): Specifies the DMAC module stop mode.

Bits 15 MSTP15	Description	
0	DMAC module stop mode cleared	(Initial value)
1	DMAC module stop mode set	

7.5 Operation

7.5.1 Transfer Modes

Table 7-5 lists the DMAC modes.

Table 7-5 DMAC Transfer Modes

Transfer Mo	de		Tr	ansfer Source	Re	emarks
Short address mode	Dual address mode	(1) Sequential mode (2) Idle mode (3) Repeat mode	•	TPU channel 0 to 5 compare match/input capture A interrupt SCI transmission data empty interrupt SCI reception data full interrupt A/D converter conversion end interrupt External request	•	Up to 4 channels can operate independently External request applies to channel B only Single address mode applies to channel B only Modes (1), (2), and (3) can also be specified for single address mode
Full address mode	., .	e address mode (5) Normal mode	•	External request Auto-request	est •	Max. 2-channel operation, combining channels A and B
		(6) Block transfer mode	•	TPU channel 0 to 5 compare match/input capture A interrupt SCI transmission data empty interrupt SCI reception data full interrupt A/D converter conversion end interrupt External request	•	With auto-request, burst mode transfer or cycle steal transfer can be selected

Operation in each mode is summarized below.

(1) Sequential mode

In response to a single transfer request, the specified number of transfers are carried out, one byte or one word at a time. An interrupt request can be sent to the CPU or DTC when the specified number of transfers have been completed. One address is specified as 24 bits, and the other as 16 bits. The transfer direction is programmable.

(2) Idle mode

In response to a single transfer request, the specified number of transfers are carried out, one byte or one word at a time. An interrupt request can be sent to the CPU or DTC when the specified number of transfers have been completed. One address is specified as 24 bits, and the other as 16 bits. The transfer source address and transfer destination address are fixed. The transfer direction is programmable.

(3) Repeat mode

In response to a single transfer request, the specified number of transfers are carried out, one byte or one word at a time. When the specified number of transfers have been completed, the addresses and transfer counter are restored to their original settings, and operation is continued. No interrupt request is sent to the CPU or DTC. One address is specified as 24 bits, and the other as 16 bits. The transfer direction is programmable.

(4) Single address mode

In response to a single transfer request, the specified number of transfers are carried out between external memory and an external device, one byte or one word at a time. Unlike dual address mode, source and destination accesses are performed in parallel. Therefore, either the source or the destination is an external device which can be accessed with a strobe alone, using the \overline{DACK} pin. One address is specified as 24 bits, and for the other, the pin is set automatically. The transfer direction is programmable.

Modes (1), (2) and (3) can also be specified for single address mode.

(5) Normal mode

Auto-request

By means of register settings only, the DMAC is activated, and transfer continues until the specified number of transfers have been completed. An interrupt request can be sent to the CPU or DTC when transfer is completed. Both addresses are specified as 24 bits.

- Cycle steal mode: The bus is released to another bus master every byte or word transfer.
- Burst mode: The bus is held and transfer continued until the specified number of transfers have been completed.

External request

In response to a single transfer request, the specified number of transfers are carried out, one byte or one word at a time. An interrupt request can be sent to the CPU or DTC when the specified number of transfers have been completed. Both addresses are specified as 24 bits.

(6) Block transfer mode

In response to a single transfer request, a block transfer of the specified block size is carried out. This is repeated the specified number of times, once each time there is a transfer request. At the end of each single block transfer, one address is restored to its original setting. An interrupt request can be sent to the CPU or DTC when the specified number of block transfers have been completed. Both addresses are specified as 24 bits.

7.5.2 Sequential Mode

Sequential mode can be specified by clearing the RPE bit in DMACR to 0. In sequential mode, MAR is updated after each byte or word transfer in response to a single transfer request, and this is executed the number of times specified in ETCR.

One address is specified by MAR, and the other by IOAR. The transfer direction can be specified by the DTDIR bit in DMACR.

Table 7-6 summarizes register functions in sequential mode.

 Table 7-6
 Register Functions in Sequential Mode

	Fur	ection			
Register	DTDIR = 0	DTDIR = 1	Initial Setting	Operation	
23 MAR	O Source address register	Destination address register	Start address of transfer destination or transfer source	Incremented/ decremented every transfer	
23 15 H'FF IOAR	O Destination address register	Source address register	Start address of transfer source or transfer destination	Fixed	
15 ETCR	7 Transfer co	unter	Number of transfers	Decremented every transfer; transfer ends when count reaches H'0000	

Legend

MAR : Memory address register
IOAR : I/O address register
ETCR : Transfer count register
DTDIR : Data transfer direction bit

MAR specifies the start address of the transfer source or transfer destination as 24 bits. MAR is incremented or decremented by 1 or 2 each time a byte or word is transferred.

IOAR specifies the lower 16 bits of the other address. The 8 bits above IOAR have a value of H'FF.

Figure 7-3 illustrates operation in sequential mode.

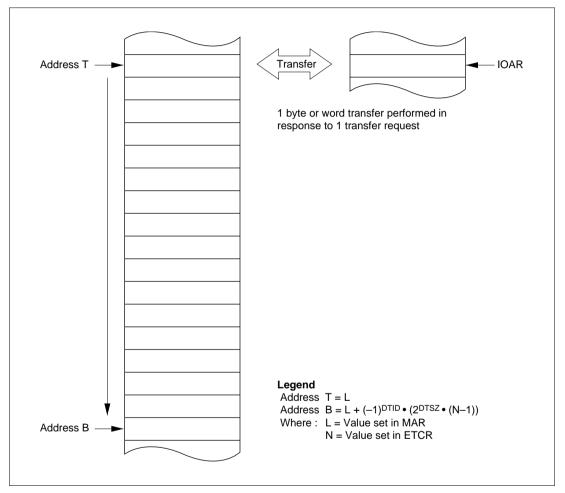


Figure 7-3 Operation in Sequential Mode

The number of transfers is specified as 16 bits in ETCR. ETCR is decremented by 1 each time a transfer is executed, and when its value reaches H'0000, the DTE bit is cleared and transfer ends. If the DTIE bit is set to 1 at this time, an interrupt request is sent to the CPU or DTC.

The maximum number of transfers, when H'0000 is set in ETCR, is 65,536.

Transfer requests (activation sources) consist of A/D converter conversion end interrupts, external requests, SCI transmission complete and reception complete interrupts, and TPU channel 0 to 5 compare match/input capture A interrupts. External requests can be set for channel B only.

Figure 7-4 shows an example of the setting procedure for sequential mode.

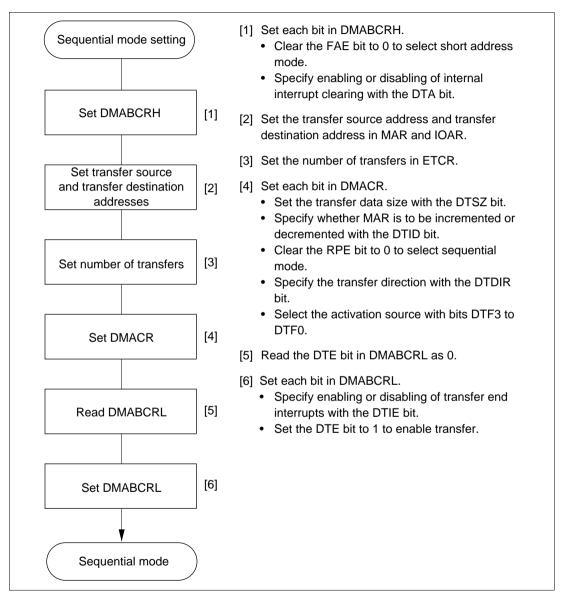


Figure 7-4 Example of Sequential Mode Setting Procedure

7.5.3 Idle Mode

Idle mode can be specified by setting the RPE bit and DTIE bit in DMACR to 1. In idle mode, one byte or word is transferred in response to a single transfer request, and this is executed the number of times specified in ETCR.

One address is specified by MAR, and the other by IOAR. The transfer direction can be specified by the DTDIR bit in DMACR.

Table 7-7 summarizes register functions in idle mode.

Table 7-7 Register Functions in Idle Mode

Function				
Register	DTDIR = 0	DTDIR = 1	Initial Setting	Operation
23 0 MAR	Source address register	Destination address register	Start address of transfer destination or transfer source	Fixed
23 15 0 H'FF IOAR	Destination address register	Source address register	Start address of transfer source or transfer destination	Fixed
15 0 ETCR	Transfer co	unter	Number of transfers	Decremented every transfer; transfer ends when count reaches H'0000

Legend

MAR : Memory address register
IOAR : I/O address register
ETCR : Transfer count register
DTDIR : Data transfer direction bit

MAR specifies the start address of the transfer source or transfer destination as 24 bits. MAR is neither incremented nor decremented each time a byte or word is transferred.

IOAR specifies the lower 16 bits of the other address. The 8 bits above IOAR have a value of H'FF.

Figure 7-5 illustrates operation in idle mode.

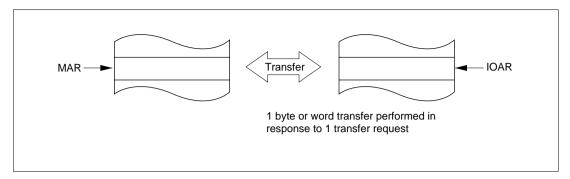


Figure 7-5 Operation in Idle Mode

The number of transfers is specified as 16 bits in ETCR. ETCR is decremented by 1 each time a transfer is executed, and when its value reaches H'0000, the DTE bit is cleared and transfer ends. If the DTIE bit is set to 1 at this time, an interrupt request is sent to the CPU or DTC.

The maximum number of transfers, when H'0000 is set in ETCR, is 65,536.

Transfer requests (activation sources) consist of A/D converter conversion end interrupts, external requests, SCI transmission complete and reception data full interrupts, and TPU channel 0 to 5 compare match/input capture A interrupts. External requests can be set for channel B only.

When the DMAC is used in single address mode, only channel B can be set.

Figure 7-6 shows an example of the setting procedure for idle mode.

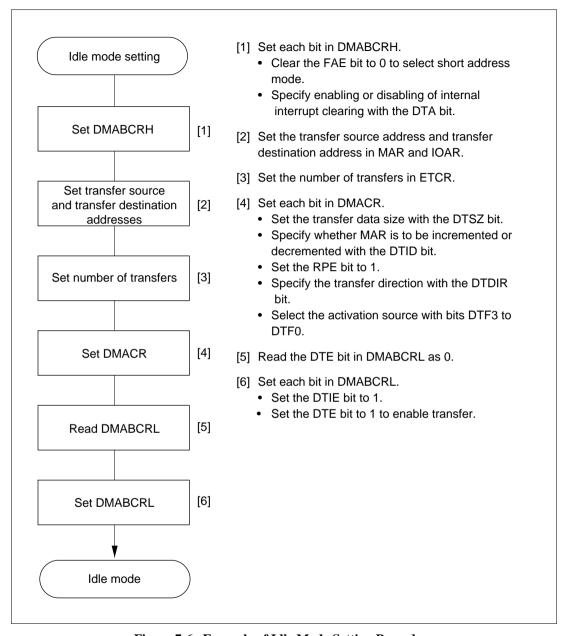


Figure 7-6 Example of Idle Mode Setting Procedure

7.5.4 Repeat Mode

Repeat mode can be specified by setting the RPE bit in DMACR to 1, and clearing the DTIE bit to 0. In repeat mode, MAR is updated after each byte or word transfer in response to a single transfer request, and this is executed the number of times specified in ETCR. On completion of the specified number of transfers, MAR and ETCRL are automatically restored to their original settings and operation continues.

One address is specified by MAR, and the other by IOAR. The transfer direction can be specified by the DTDIR bit in DMACR.

Table 7-8 summarizes register functions in repeat mode.

Table 7-8 Register Functions in Repeat Mode

	Function			
Register	DTDIR = 0	DTDIR = 1	Initial Setting	Operation
23 0 MAR	Source address register	Destination address register	Start address of transfer destination or transfer source	Incremented/ decremented every transfer. Initial setting is restored when value reaches H'0000
23 15 0 H'FF IOAR	Destination address register	Source address register	Start address of transfer source or transfer destination	Fixed
7 0 ETCRH	Holds numb transfers	er of	Number of transfers	Fixed
7 ▼ 0 ETCRL	Transfer co	unter	Number of transfers	Decremented every transfer. Loaded with ETCRH value when count reaches H'00

Legend

MAR : Memory address register
IOAR : I/O address register
ETCR : Transfer count register
DTDIR : Data transfer direction bit

MAR specifies the start address of the transfer source or transfer destination as 24 bits. MAR is incremented or decremented by 1 or 2 each time a byte or word is transferred.

IOAR specifies the lower 16 bits of the other address. The 8 bits above IOAR have a value of H'FF.

The number of transfers is specified as 8 bits by ETCRH and ETCRL. The maximum number of transfers, when H'00 is set in both ETCRH and ETCRL, is 256.

In repeat mode, ETCRL functions as the transfer counter, and ETCRH is used to hold the number of transfers. ETCRL is decremented by 1 each time a transfer is executed, and when its value reaches H'00, it is loaded with the value in ETCRH. At the same time, the value set in MAR is restored in accordance with the values of the DTSZ and DTID bits in DMACR. The MAR restoration operation is as shown below.

$$MAR = MAR - (-1)^{DTID} \cdot 2^{DTSZ} \cdot ETCRH$$

The same value should be set in ETCRH and ETCRL.

In repeat mode, operation continues until the DTE bit is cleared. To end the transfer operation, therefore, you should clear the DTE bit to 0. A transfer end interrupt request is not sent to the CPU or DTC.

By setting the DTE bit to 1 again after it has been cleared, the operation can be restarted from the transfer after that terminated when the DTE bit was cleared.

Figure 7-7 illustrates operation in repeat mode.

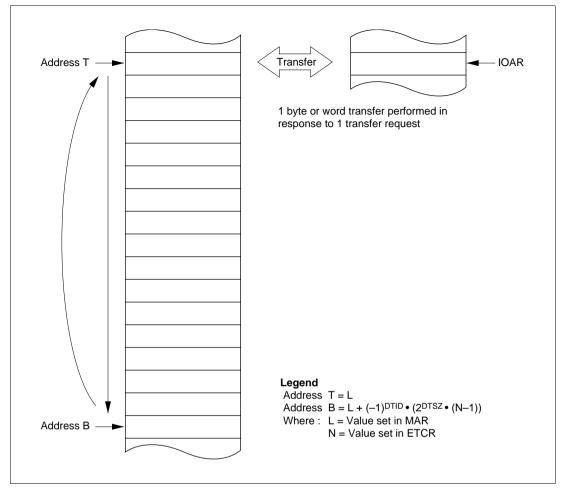


Figure 7-7 Operation in Repeat mode

Transfer requests (activation sources) consist of A/D converter conversion end interrupts, external requests, SCI transmission complete and reception data full interrupts, and TPU channel 0 to 5 compare match/input capture A interrupts. External requests can be set for channel B only.

Figure 7-8 shows an example of the setting procedure for repeat mode.

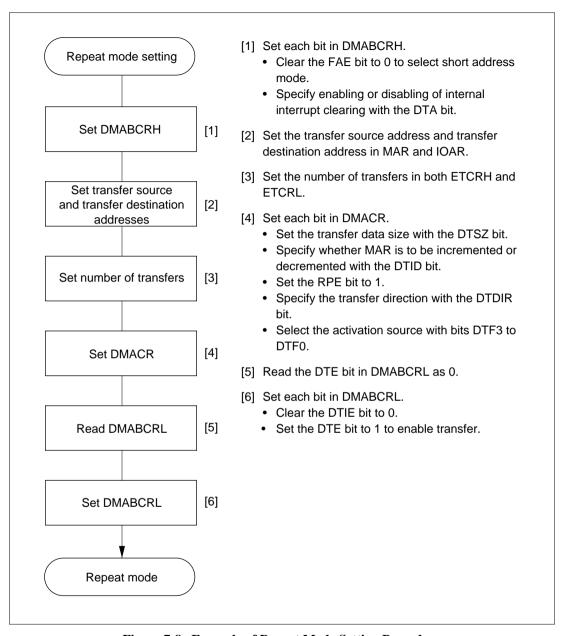


Figure 7-8 Example of Repeat Mode Setting Procedure

7.5.5 Single Address Mode

Single address mode can only be specified for channel B. This mode can be specified by setting the SAE bit in DMABCR to 1 in short address mode.

One address is specified by MAR, and the other is set automatically to the data transfer acknowledge pin (\overline{DACK}) . The transfer direction can be specified by the DTDIR in DMACR.

Table 7-9 summarizes register functions in single address mode.

Table 7-9 Register Functions in Single Address Mode

Function					
Register	DTDIR = 0	DTDIR = 1	Initial Setting	Operation	
23 0 MAR	Source address register	Destination address register	Start address of transfer destination or transfer source	*	
DACK pin	Write strobe	Read strobe	(Set automatically by SAE bit; IOAR is invalid)	Strobe for external device	
15 0 ETCR	Transfer co	unter	Number of transfers	*	

Legend

MAR : Memory address register
IOAR : I/O address register
ETCR : Transfer count register
DTDIR : Data transfer direction bit
DACK : Data transfer acknowledge

Note: * See the operation descriptions in sections 7.5.2, Sequential Mode, 7.5.3, Idle Mode, and 7.5.4, Repeat Mode.

MAR specifies the start address of the transfer source or transfer destination as 24 bits.

IOAR is invalid; in its place the strobe for external devices (\overline{DACK}) is output.

Figure 7-9 illustrates operation in single address mode (when sequential mode is specified).

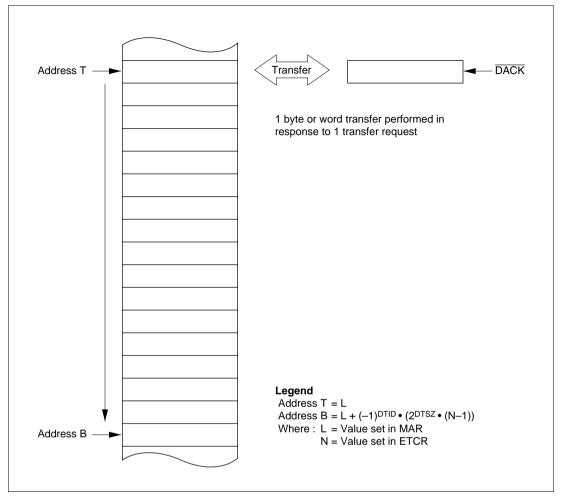


Figure 7-9 Operation in Single Address Mode (When Sequential Mode is Specified)

Figure 7-10 shows an example of the setting procedure for single address mode (when sequential mode is specified).

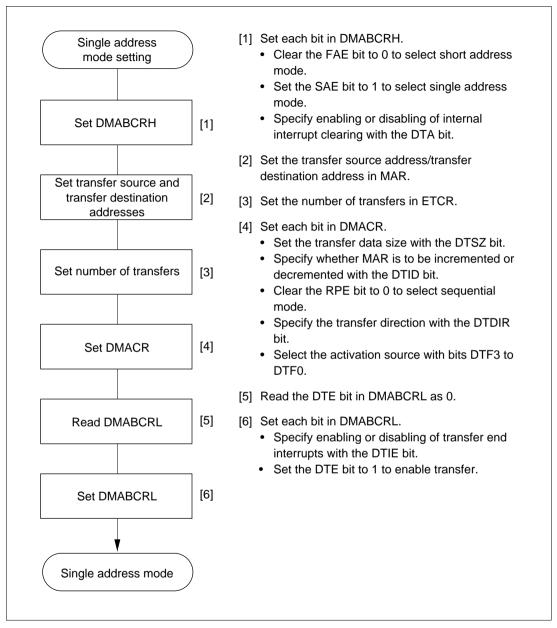


Figure 7-10 Example of Single Address Mode Setting Procedure (When Sequential Mode is Specified)

7.5.6 Normal Mode

In normal mode, transfer is performed with channels A and B used in combination. Normal mode can be specified by setting the FAE bit in DMABCR to 1 and clearing the BLKE bit in DMACRA to 0.

In normal mode, MAR is updated after each byte or word transfer in response to a single transfer request, and this is executed the number of times specified in ETCRA. The transfer source is specified by MARA, and the transfer destination by MARB.

Table 7-10 summarizes register functions in normal mode.

Table 7-10 Register Functions in Normal Mode

Registe	r	Function	Initial Setting	Operation
23	MARA	O Source address register	Start address of transfer source	Incremented/decremented every transfer, or fixed
23	MARB	0 Destination address register	Start address of transfer destination	Incremented/decremented every transfer, or fixed
	15 ETÇRA	0 Transfer counter	Number of transfers	Decremented every transfer; transfer ends when count reaches H'0000

Legend

MARA: Memory address register A MARB: Memory address register B ETCRA: Transfer count register A

MARA and MARB specify the start addresses of the transfer source and transfer destination, respectively, as 24 bits. MAR can be incremented or decremented by 1 or 2 each time a byte or word is transferred, or can be fixed.

Incrementing, decrementing, or holding a fixed value can be set separately for MARA and MARB.

The number of transfers is specified by ETCRA as 16 bits. ETCRA is decremented each time a transfer is performed, and when its value reaches H'0000 the DTE bit is cleared and transfer ends. If the DTIE bit is set to 1 at this time, an interrupt request is sent to the CPU or DTC.

The maximum number of transfers, when H'0000 is set in ETCRA, is 65,536.

Figure 7-11 illustrates operation in normal mode.

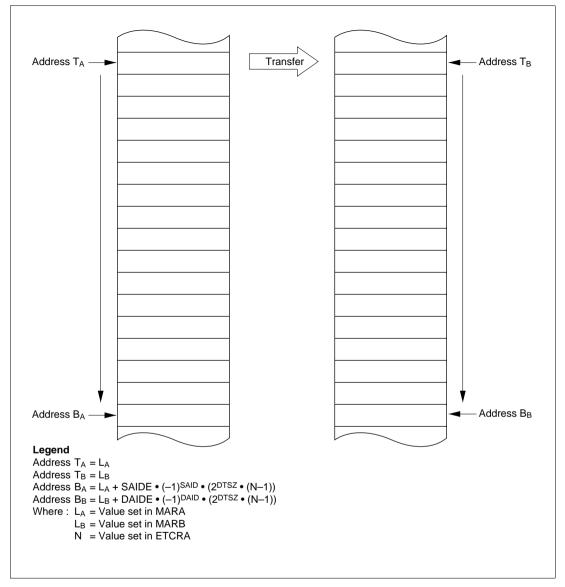


Figure 7-11 Operation in Normal Mode

Transfer requests (activation sources) are external requests and auto-requests.

With auto-request, the DMAC is only activated by register setting, and the specified number of transfers are performed automatically. With auto-request, cycle steal mode or burst mode can be selected. In cycle steal mode, the bus is released to another bus master each time a transfer is performed. In burst mode, the bus is held continuously until transfer ends.

For setting details, see section 7.3.4, DMA Controller Register (DMACR).

Figure 7-12 shows an example of the setting procedure for normal mode.

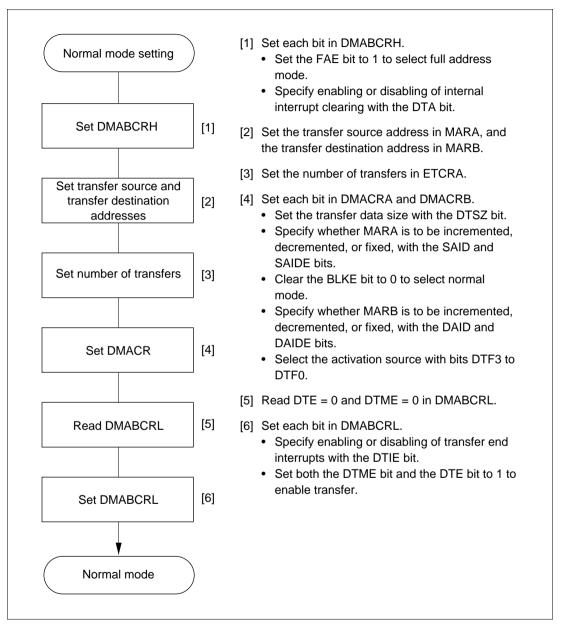


Figure 7-12 Example of Normal Mode Setting Procedure

7.5.7 Block Transfer Mode

In block transfer mode, transfer is performed with channels A and B used in combination. Block transfer mode can be specified by setting the FAE bit in DMABCR and the BLKE bit in DMACRA to 1.

In block transfer mode, a transfer of the specified block size is carried out in response to a single transfer request, and this is executed the specified number of times. The transfer source is specified by MARA, and the transfer destination by MARB. Either the transfer source or the transfer destination can be selected as a block area (an area composed of a number of bytes or words).

Table 7-11 summarizes register functions in block transfer mode.

Table 7-11 Register Functions in Block Transfer Mode

Register	Function	Initial Setting	Operation
23 MARA	O Source address register	Start address of transfer source	Incremented/decremented every transfer, or fixed
23 MARB	Destination address register	Start address of transfer destination	Incremented/decremented every transfer, or fixed
7 ETCRAH	Holds block size	Block size	Fixed
7 TETCRAL	Block size counter	Block size	Decremented every transfer; ETCRH value copied when count reaches H'00
15 ETCRB	Block transfer counter	Number of block transfers	Decremented every block transfer; transfer ends when count reaches H'0000

Legend

MARA: Memory address register A MARB: Memory address register B ETCRA: Transfer count register A ETCRB: Transfer count register B

MARA and MARB specify the start addresses of the transfer source and transfer destination, respectively, as 24 bits. MAR can be incremented or decremented by 1 or 2 each time a byte or word is transferred, or can be fixed.

Incrementing, decrementing, or holding a fixed value can be set separately for MARA and MARB.

Whether a block is to be designated for MARA or for MARB is specified by the BLKDIR bit in DMACRA.

To specify the number of transfers, if M is the size of one block (where M=1 to 256) and N transfers are to be performed (where N=1 to 65,536), M is set in both ETCRAH and ETCRAL, and N in ETCRB.

Figure 7-13 illustrates operation in block transfer mode when MARB is designated as a block area.

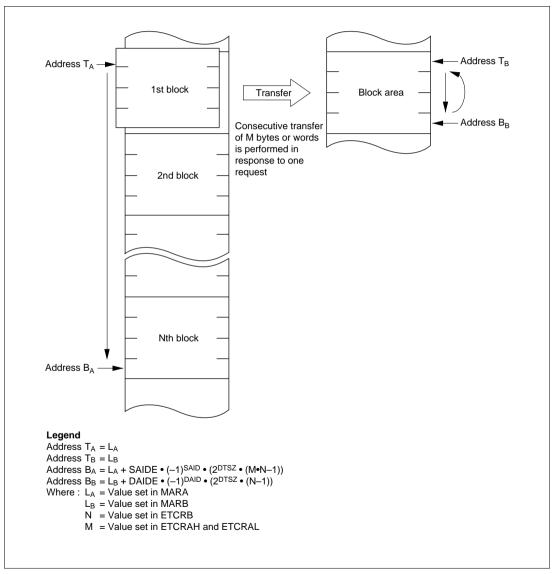


Figure 7-13 Operation in Block Transfer Mode (BLKDIR = 0)

Figure 7-14 illustrates operation in block transfer mode when MARA is designated as a block area.

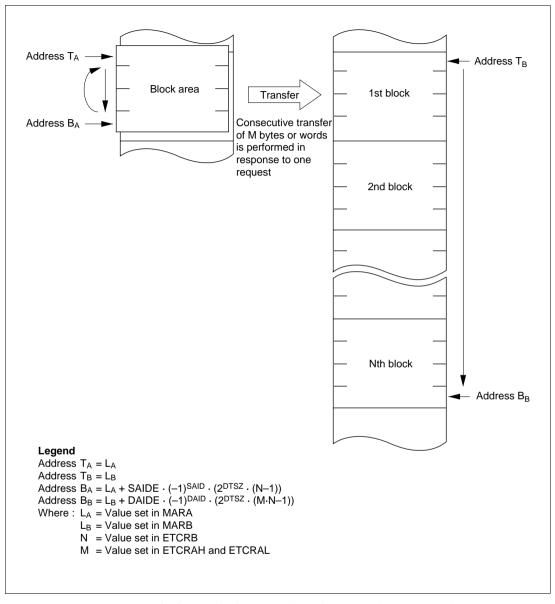


Figure 7-14 Operation in Block Transfer Mode (BLKDIR = 1)

ETCRAL is decremented by 1 each time a byte or word transfer is performed. In response to a single transfer request, burst transfer is performed until the value in ETCRAL reaches H'00. ETCRAL is then loaded with the value in ETCRAH. At this time, the value in the MAR register for which a block designation has been given by the BLKDIR bit in DMACRA is restored in accordance with the DTSZ, SAID/DAID, and SAIDE/DAIDE bits in DMACR.

ETCRB is decremented by 1 every block transfer, and when the count reaches H'0000 the DTE bit is cleared and transfer ends. If the DTIE bit is set to 1 at this point, an interrupt request is sent to the CPU or DTC.

Figure 7-15 shows the operation flow in block transfer mode.

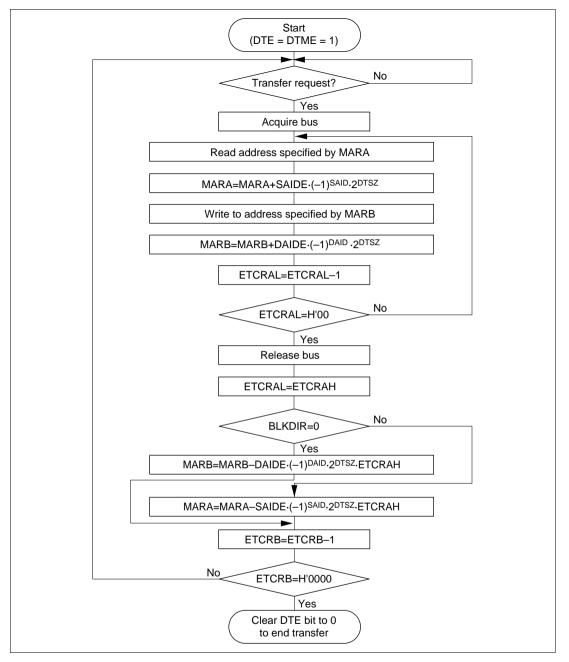


Figure 7-15 Operation Flow in Block Transfer Mode

Transfer requests (activation sources) consist of A/D converter conversion end interrupts, external requests, SCI transmission complete and reception data full interrupts, and TPU channel 0 to 5 compare match/input capture A interrupts.

For details, see section 7.3.4, DMA Control Register (DMACR).

Figure 7-16 shows an example of the setting procedure for block transfer mode.

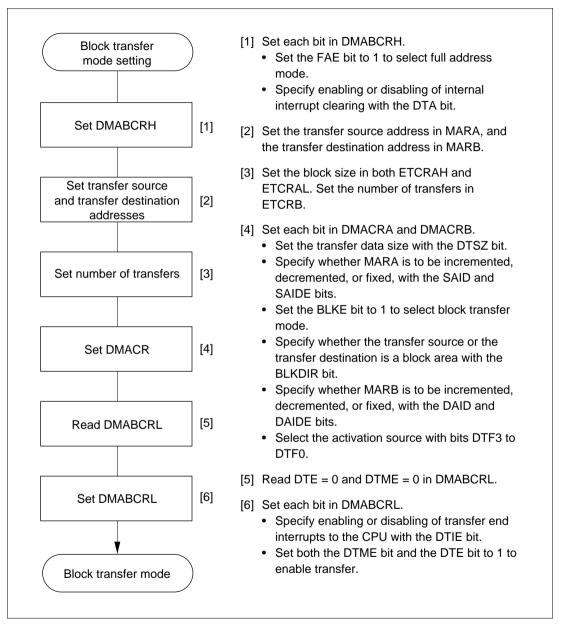


Figure 7-16 Example of Block Transfer Mode Setting Procedure

7.5.8 DMAC Activation Sources

DMAC activation sources consist of internal interrupts, external requests, and auto-requests. The activation sources that can be specified depend on the transfer mode and the channel, as shown in table 7-12.

Table 7-12 DMAC Activation Sources

		Short Add	ress Mode	Full Address Mode		
Activation Source		Channels 0A and 1A	Channels 0B and 1B	Normal Mode	Block Transfer Mode	
Internal	ADI	0	0	Х	0	
Interrupts	TXI0	0	0	Х	0	
	RXI0	0	0	Χ	0	
	TXI1	0	0	Х	0	
	RXI1	0	0	Х	0	
	TGI0A	0	0	Х	0	
	TGI1A	0	0	Χ	0	
	TGI2A	0	0	Х	0	
	TGI3A	0	0	Х	0	
	TGI4A	0	0	Χ	0	
	TGI5A	0	0	Х	0	
External Requests	DREQ pin falling edge input	Х	0	0	0	
	DREQ pin low-level input	Х	0	0	0	
Auto-request		Х	Χ	0	Χ	

Legend

Can be specifiedX : Cannot be specified

Activation by Internal Interrupt: An interrupt request selected as a DMAC activation source can be sent simultaneously to the CPU and DTC. For details, see section 5, Interrupt Controller.

With activation by an internal interrupt, the DMAC accepts the request independently of the interrupt controller. Consequently, interrupt controller priority settings are not accepted.

If the DMAC is activated by a CPU interrupt source or an interrupt source that is not used as a DTC activation source (DTA = 1), the interrupt source flag is cleared automatically by the DMA transfer. With ADI, TXI, and RXI interrupts, however, the interrupt source flag is not cleared unless the prescribed register is accessed in a DMA transfer. If the same interrupt is used as an

activation source for more than one channel, the interrupt request flag is cleared when the highestpriority channel is activated first. Transfer requests for other channels are held pending in the DMAC, and activation is carried out in order of priority.

When DTE = 0, such as after completion of a transfer, a request from the selected activation source is not sent to the DMAC, regardless of the DTA bit. In this case, the relevant interrupt request is sent to the CPU or DTC.

In case of overlap with a CPU interrupt source or DTC activation source (DTA = 0), the interrupt request flag is not cleared by the DMAC.

Activation by External Request: If an external request (\overline{DREQ} pin) is specified as an activation source, the relevant port should be set to input mode in advance.

Level sensing or edge sensing can be used for external requests.

External request operation in normal mode (short address mode or full address mode) is described below.

When edge sensing is selected, a 1-byte or 1-word transfer is executed each time a high-to-low transition is detected on the \overline{DREQ} pin. The next transfer may not be performed if the next edge is input before transfer is completed.

When level sensing is selected, the DMAC stands by for a transfer request while the \overline{DREQ} pin is held high. While the \overline{DREQ} pin is held low, transfers continue in succession, with the bus being released each time a byte or word is transferred. If the \overline{DREQ} pin goes high in the middle of a transfer, the transfer is interrupted and the DMAC stands by for a transfer request.

Activation by Auto-Request: Auto-request activation is performed by register setting only, and transfer continues to the end.

With auto-request activation, cycle steal mode or burst mode can be selected.

In cycle steal mode, the DMAC releases the bus to another bus master each time a byte or word is transferred. DMA and CPU cycles usually alternate.

In burst mode, the DMAC keeps possession of the bus until the end of the transfer, and transfer is performed continuously.

Single Address Mode: The DMAC can operate in dual address mode in which read cycles and write cycles are separate cycles, or single address mode in which read and write cycles are executed in parallel.

In dual address mode, transfer is performed with the source address and destination address specified separately.

In single address mode, on the other hand, transfer is performed between external space in which either the transfer source or the transfer destination is specified by an address, and an external device for which selection is performed by means of the \overline{DACK} strobe, without regard to the address. Figure 7-16 shows the data bus in single address mode.

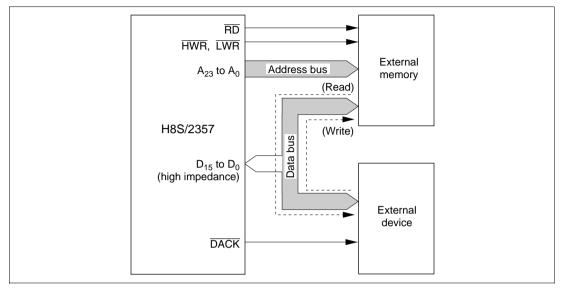


Figure 7-17 Data Bus in Single Address Mode

When using the DMAC for single address mode reading, transfer is performed from external memory to the external device, and the \overline{DACK} pin functions as a write strobe for the external device. When using the DMAC for single address mode writing, transfer is performed from the external device to external memory, and the \overline{DACK} pin functions as a read strobe for the external device. Since there is no directional control for the external device, one or other of the above single directions should be used.

Bus cycles in single address mode are in accordance with the settings of the bus controller for the external memory area. On the external device side, \overline{DACK} is output in synchronization with the address strobe. For details of bus cycles, see section 7.5.11, DMAC Bus Cycles (Single Address Mode).

Do not specify internal space for transfer addresses in single address mode.

7.5.9 Basic DMAC Bus Cycles

An example of the basic DMAC bus cycle timing is shown in figure 7-18. In this example, word-size transfer is performed from 16-bit, 2-state access space to 8-bit, 3-state access space. When the bus is transferred from the CPU to the DMAC, a source address read and destination address write are performed. The bus is not released in response to another bus request, etc., between these read and write operations. As with CPU cycles, DMA cycles conform to the bus controller settings.

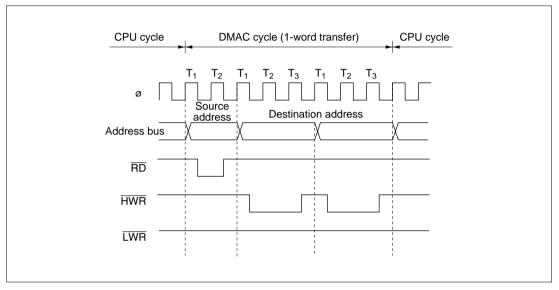


Figure 7-18 Example of DMA Transfer Bus Timing

The address is not output to the external address bus in an access to on-chip memory or an internal I/O register.

7.5.10 DMAC Bus Cycles (Dual Address Mode)

Short Address Mode: Figure 7-19 shows a transfer example in which TEND output is enabled and byte-size short address mode transfer (sequential/idle/repeat mode) is performed from external 8-bit, 2-state access space to internal I/O space.

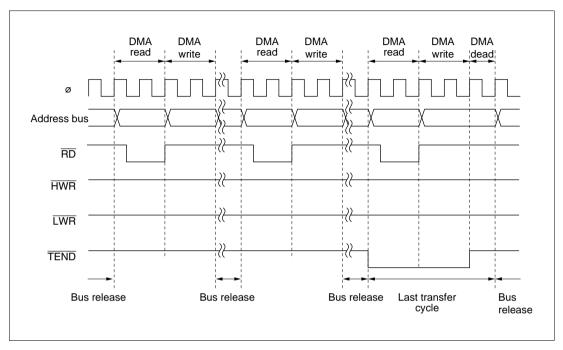


Figure 7-19 Example of Short Address Mode Transfer

A one-byte or one-word transfer is performed for one transfer request, and after the transfer the bus is released. While the bus is released one or more bus cycles are inserted by the CPU or DTC.

In the transfer end cycle (the cycle in which the transfer counter reaches 0), a one-state DMA dead cycle is inserted after the DMA write cycle.

In repeat mode, when $\overline{\text{TEND}}$ output is enabled, $\overline{\text{TEND}}$ output goes low in the transfer cycle in which the transfer counter reaches 0.

Full Address Mode (Cycle Steal Mode): Figure 7-20 shows a transfer example in which TEND output is enabled and word-size full address mode transfer (cycle steal mode) is performed from external 16-bit, 2-state access space to external 16-bit, 2-state access space.

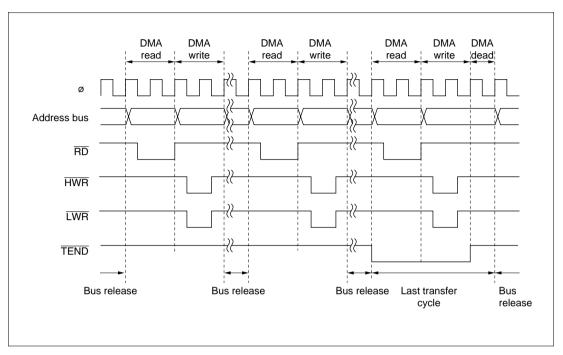


Figure 7-20 Example of Full Address Mode (Cycle Steal) Transfer

A one-byte or one-word transfer is performed, and after the transfer the bus is released. While the bus is released one bus cycle is inserted by the CPU or DTC.

In the transfer end cycle (the cycle in which the transfer counter reaches 0), a one-state DMA dead cycle is inserted after the DMA write cycle.

Full Address Mode (Burst Mode): Figure 7-21 shows a transfer example in which $\overline{\text{TEND}}$ output is enabled and word-size full address mode transfer (burst mode) is performed from external 16-bit, 2-state access space to external 16-bit, 2-state access space.

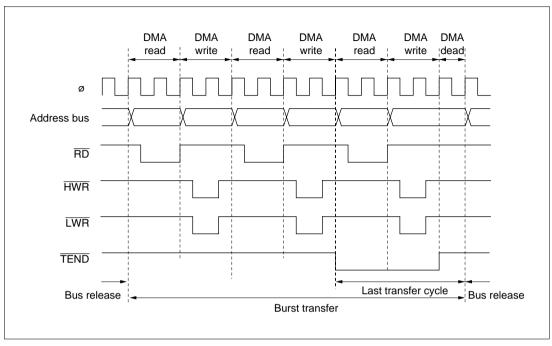


Figure 7-21 Example of Full Address Mode (Burst Mode) Transfer

In burst mode, one-byte or one-word transfers are executed consecutively until transfer ends.

In the transfer end cycle (the cycle in which the transfer counter reaches 0), a one-state DMA dead cycle is inserted after the DMA write cycle.

If a request from another higher-priority channel is generated after burst transfer starts, that channel has to wait until the burst transfer ends.

If an NMI is generated while a channel designated for burst transfer is in the transfer enabled state, the DTME bit is cleared and the channel is placed in the transfer disabled state. If burst transfer has already been activated inside the DMAC, the bus is released on completion of a one-byte or one-word transfer within the burst transfer, and burst transfer is suspended. If the last transfer cycle of the burst transfer has already been activated inside the DMAC, execution continues to the end of the transfer even if the DTME bit is cleared.

Full Address Mode (Block Transfer Mode): Figure 7-22 shows a transfer example in which TEND output is enabled and word-size full address mode transfer (block transfer mode) is performed from internal 16-bit, 1-state access space to external 16-bit, 2-state access space.

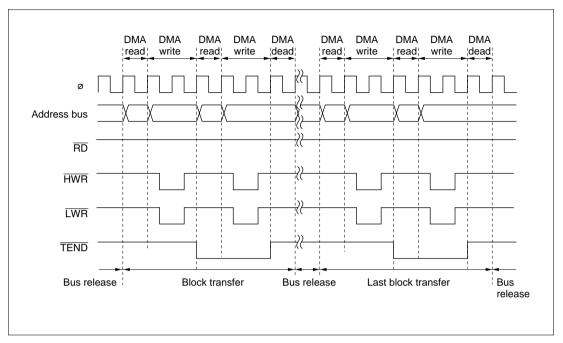


Figure 7-22 Example of Full Address Mode (Block Transfer Mode) Transfer

A one-block transfer is performed for one transfer request, and after the transfer the bus is released. While the bus is released, one or more bus cycles are inserted by the CPU or DTC.

In the transfer end cycle of each block (the cycle in which the transfer counter reaches 0), a one-state DMA dead cycle is inserted after the DMA write cycle.

One block is transmitted without interruption. NMI generation does not affect block transfer operation.

DREQ Pin Falling Edge Activation Timing: Set the DTA bit for the channel for which the DREQ pin is selected to 1.

Figure 7-23 shows an example of \overline{DREQ} pin falling edge activated normal mode transfer.

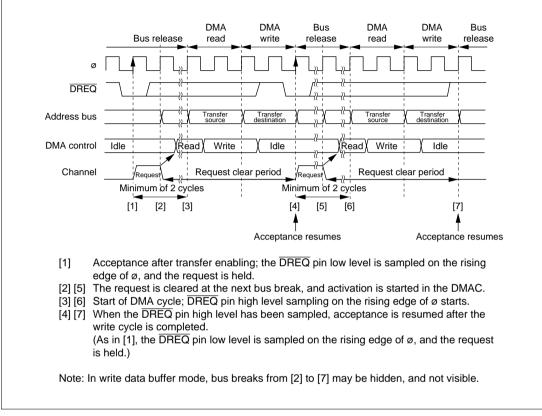
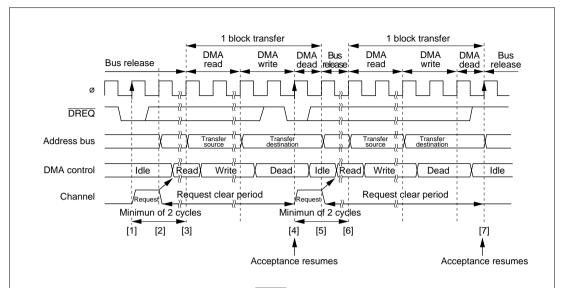


Figure 7-23 Example of DREQ Pin Falling Edge Activated Normal Mode Transfer

DREQ pin sampling is performed every cycle, with the rising edge of the next ø cycle after the end of the DMABCR write cycle for setting the transfer enabled state as the starting point.

When the \overline{DREQ} pin low level is sampled while acceptance by means of the \overline{DREQ} pin is possible, the request is held in the DMAC. Then, when activation is initiated in the DMAC, the request is cleared, and \overline{DREQ} pin high level sampling for edge detection is started. If \overline{DREQ} pin high level sampling has been completed by the time the DMA write cycle ends, acceptance resumes after the end of the write cycle, \overline{DREQ} pin low level sampling is performed again, and this operation is repeated until the transfer ends.

Figure 7-24 shows an example of DREQ pin falling edge activated block transfer mode transfer.



- [1] Acceptance after transfer enabling; the DREQ pin low level is sampled on the rising edge of ø, and the request is held.
- [2] [5] The request is cleared at the next bus break, and activation is started in the DMAC.
- [3] [6] Start of DMA cycle; DREQ pin high level sampling on the rising edge of ø starts.
- [4] [7] When the DREQ pin high level has been sampled, acceptance is resumed after the dead cycle is completed.
 (As in [1], the DREQ pin low level is sampled on the rising edge of ø, and the request is held.)

Note: In write data buffer mode, bus breaks from [2] to [7] may be hidden, and not visible.

Figure 7-24 Example of DREO Pin Falling Edge Activated Block Transfer Mode Transfer

DREQ pin sampling is performed every cycle, with the rising edge of the next ø cycle after the end of the DMABCR write cycle for setting the transfer enabled state as the starting point.

When the \overline{DREQ} pin low level is sampled while acceptance by means of the \overline{DREQ} pin is possible, the request is held in the DMAC. Then, when activation is initiated in the DMAC, the request is cleared, and \overline{DREQ} pin high level sampling for edge detection is started. If \overline{DREQ} pin high level sampling has been completed by the time the DMA dead cycle ends, acceptance resumes after the end of the dead cycle, \overline{DREQ} pin low level sampling is performed again, and this operation is repeated until the transfer ends.

DREQ Level Activation Timing (Normal Mode): Set the DTA bit for the channel for which the DREQ pin is selected to 1.

Figure 7-25 shows an example of \overline{DREQ} level activated normal mode transfer.

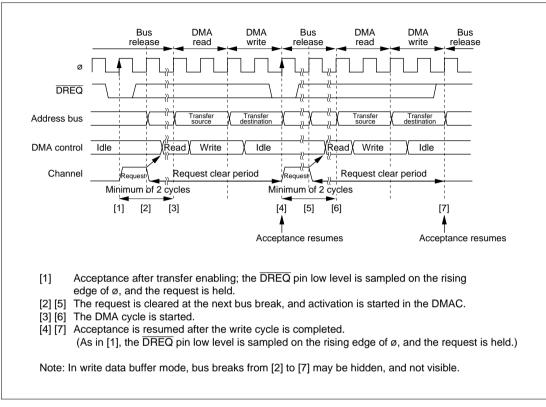
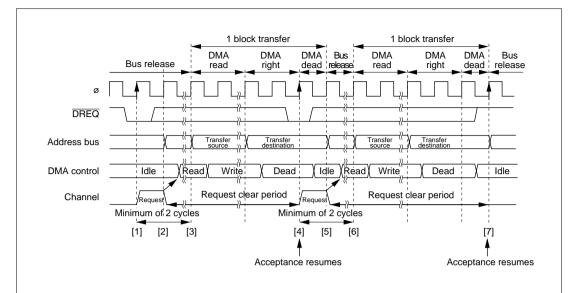


Figure 7-25 Example of DREQ Level Activated Normal Mode Transfer

DREQ pin sampling is performed every cycle, with the rising edge of the next ø cycle after the end of the DMABCR write cycle for setting the transfer enabled state as the starting point.

When the \overline{DREQ} pin low level is sampled while acceptance by means of the \overline{DREQ} pin is possible, the request is held in the DMAC. Then, when activation is initiated in the DMAC, the request is cleared. After the end of the write cycle, acceptance resumes, \overline{DREQ} pin low level sampling is performed again, and this operation is repeated until the transfer ends.

Figure 7-26 shows an example of DREQ level activated block transfer mode transfer.



- [1] Acceptance after transfer enabling; the DREQ pin low level is sampled on the rising edge of ø, and the request is held.
- [2] [5] The request is cleared at the next bus break, and activation is started in the DMAC.
- [3] [6] The DMA cycle is started.
- [4] [7] Acceptance is resumed after the dead cycle is completed.

 (As in [1], the DREQ pin low level is sampled on the rising edge of ø, and the request is held.)

Note: In write data buffer mode, bus breaks from [2] to [7] may be hidden, and not visible.

Figure 7-26 Example of DREQ Level Activated Block Transfer Mode Transfer

DREQ pin sampling is performed every cycle, with the rising edge of the next ø cycle after the end of the DMABCR write cycle for setting the transfer enabled state as the starting point.

When the \overline{DREQ} pin low level is sampled while acceptance by means of the \overline{DREQ} pin is possible, the request is held in the DMAC. Then, when activation is initiated in the DMAC, the request is cleared. After the end of the dead cycle, acceptance resumes, \overline{DREQ} pin low level sampling is performed again, and this operation is repeated until the transfer ends.

7.5.11 DMAC Bus Cycles (Single Address Mode)

Single Address Mode (Read): Figure 7-27 shows a transfer example in which TEND output is enabled and byte-size single address mode transfer (read) is performed from external 8-bit, 2-state access space to an external device.

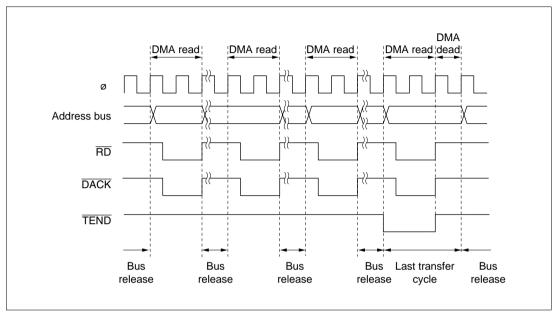


Figure 7-27 Example of Single Address Mode (Byte Read) Transfer

Figure 7-28 shows a transfer example in which $\overline{\text{TEND}}$ output is enabled and word-size single address mode transfer (read) is performed from external 8-bit, 2-state access space to an external device.

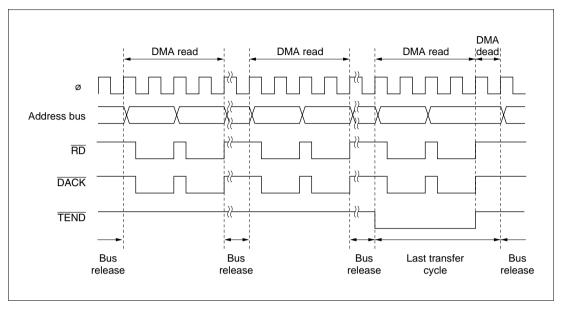


Figure 7-28 Example of Single Address Mode (Word Read) Transfer

A one-byte or one-word transfer is performed for one transfer request, and after the transfer the bus is released. While the bus is released, one or more bus cycles are inserted by the CPU or DTC.

In the transfer end cycle (the cycle in which the transfer counter reaches 0), a one-state DMA dead cycle is inserted after the DMA write cycle.

Single Address Mode (Write): Figure 7-29 shows a transfer example in which TEND output is enabled and byte-size single address mode transfer (write) is performed from an external device to external 8-bit, 2-state access space.

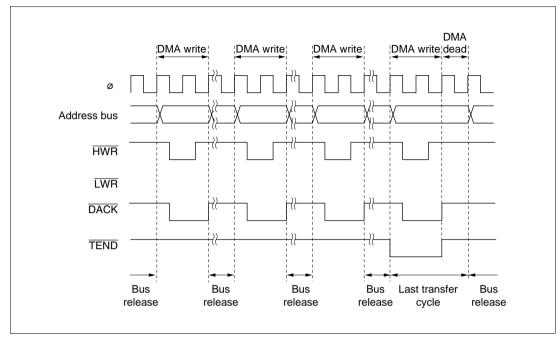


Figure 7-29 Example of Single Address Mode (Byte Write) Transfer

Figure 7-30 shows a transfer example in which $\overline{\text{TEND}}$ output is enabled and word-size single address mode transfer (write) is performed from an external device to external 8-bit, 2-state access space.

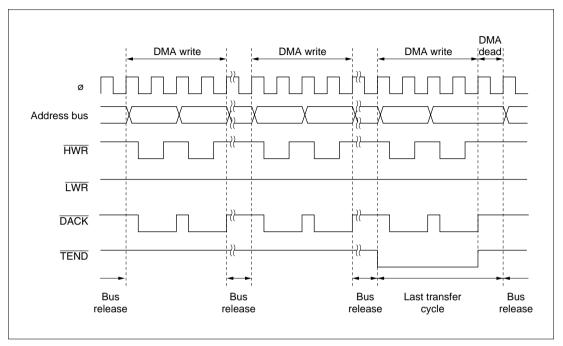


Figure 7-30 Example of Single Address Mode (Word Write) Transfer

A one-byte or one-word transfer is performed for one transfer request, and after the transfer the bus is released. While the bus is released one or more bus cycles are inserted by the CPU or DTC.

In the transfer end cycle (the cycle in which the transfer counter reaches 0), a one-state DMA dead cycle is inserted after the DMA write cycle.

DREQ Pin Falling Edge Activation Timing: Set the DTA bit for the channel for which the DREQ pin is selected to 1.

Figure 7-31 shows an example of \overline{DREQ} pin falling edge activated single address mode transfer.

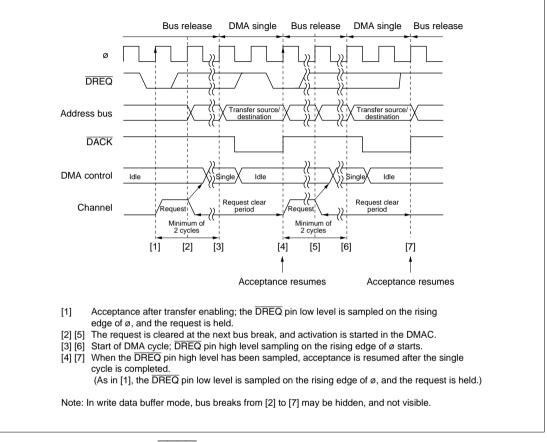


Figure 7-31 Example of DREQ Pin Falling Edge Activated Single Address Mode Transfer

DREQ pin sampling is performed every cycle, with the rising edge of the next ø cycle after the end of the DMABCR write cycle for setting the transfer enabled state as the starting point.

When the \overline{DREQ} pin low level is sampled while acceptance by means of the \overline{DREQ} pin is possible, the request is held in the DMAC. Then, when activation is initiated in the DMAC, the request is cleared, and \overline{DREQ} pin high level sampling for edge detection is started. If \overline{DREQ} pin high level sampling has been completed by the time the DMA single cycle ends, acceptance resumes after the end of the single cycle, \overline{DREQ} pin low level sampling is performed again, and this operation is repeated until the transfer ends.

 $\overline{\text{DREQ}}$ Pin Low Level Activation Timing: Set the DTA bit for the channel for which the $\overline{\text{DREQ}}$ pin is selected to 1.

Figure 7-32 shows an example of \overline{DREQ} pin low level activated single address mode transfer.

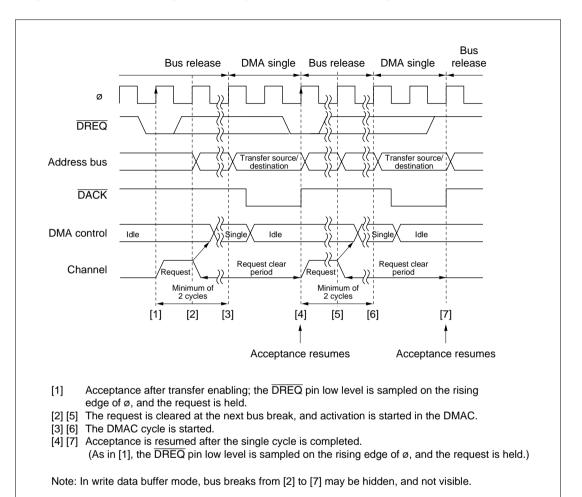


Figure 7-32 Example of DREQ Pin Low Level Activated Single Address Mode Transfer

DREQ pin sampling is performed every cycle, with the rising edge of the next ø cycle after the end of the DMABCR write cycle for setting the transfer enabled state as the starting point.

When the \overline{DREQ} pin low level is sampled while acceptance by means of the \overline{DREQ} pin is possible, the request is held in the DMAC. Then, when activation is initiated in the DMAC, the request is cleared. After the end of the single cycle, acceptance resumes, \overline{DREQ} pin low level sampling is performed again, and this operation is repeated until the transfer ends.

7.5.12 Write Data Buffer Function

DMAC internal-to-external dual address transfers and single address transfers can be executed at high speed using the write data buffer function, enabling system throughput to be improved.

When the WDBE bit of BCRL in the bus controller is set to 1, enabling the write data buffer function, dual address transfer external write cycles or single address transfers and internal accesses (on-chip memory or internal I/O registers) are executed in parallel. Internal accesses are independent of the bus master, and DMAC dead cycles are regarded as internal accesses.

A low level can always be output from the \overline{TEND} pin if the bus cycle in which a low level is to be output is an external bus cycle. However, a low level is not output from the \overline{TEND} pin if the bus cycle in which a low level is to be output from the \overline{TEND} pin is an internal bus cycle, and an external write cycle is executed in parallel with this cycle.

Figure 7-33 shows an example of burst mode transfer from on-chip RAM to external memory using the write data buffer function.

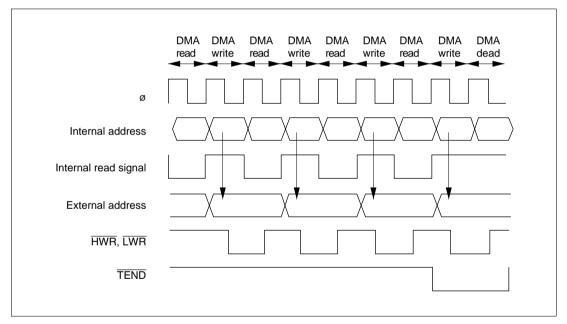


Figure 7-33 Example of Dual Address Transfer Using Write Data Buffer Function

Figure 7-34 shows an example of single address transfer using the write data buffer function. In this example, the CPU program area is in on-chip memory.

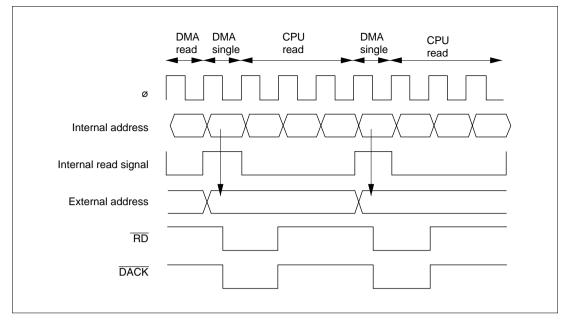


Figure 7-34 Example of Single Address Transfer Using Write Data Buffer Function

When the write data buffer function is activated, the DMAC recognizes that the bus cycle concerned has ended, and starts the next operation. Therefore, \overline{DREQ} pin sampling is started one state after the start of the DMA write cycle or single address transfer.

7.5.13 DMAC Multi-Channel Operation

The DMAC channel priority order is: channel 0 > channel 1, and channel A > channel B. Table 7-13 summarizes the priority order for DMAC channels.

Table 7-13 DMAC Channel Priority Order

Short Address Mode	Full Address Mode	Priority	
Channel 0A	Channel 0	High	
Channel 0B		A	
Channel 1A	Channel 1		
Channel 1B		Low	

If transfer requests are issued simultaneously for more than one channel, or if a transfer request for another channel is issued during a transfer, when the bus is released the DMAC selects the highest-priority channel from among those issuing a request according to the priority order shown in table 7-13.

During burst transfer, or when one block is being transferred in block transfer, the channel will not be changed until the end of the transfer.

Figure 7-35 shows a transfer example in which transfer requests are issued simultaneously for channels 0A, 0B, and 1.

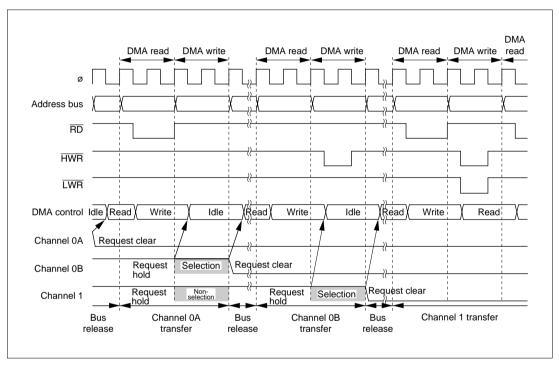


Figure 7-35 Example of Multi-Channel Transfer

7.5.14 Relation Between External Bus Requests, Refresh Cycles, the DTC, and the DMAC

There can be no break between a DMA cycle read and a DMA cycle write. This means that a refresh cycle, external bus release cycle, or DTC cycle is not generated between the external read and external write in a DMA cycle.

In the case of successive read and write cycles, such as in burst transfer or block transfer, a refresh or external bus released state may be inserted after a write cycle. Since the DTC has a lower priority than the DMAC, the DTC does not operate until the DMAC releases the bus.

When DMA cycle reads or writes are accesses to on-chip memory or internal I/O registers, these DMA cycles can be executed at the same time as refresh cycles or external bus release. However, simultaneous operation may not be possible when a write buffer is used.

7.5.15 NMI Interrupts and DMAC

When an NMI interrupt is requested, burst mode transfer in full address mode is interrupted. An NMI interrupt does not affect the operation of the DMAC in other modes.

In full address mode, transfer is enabled for a channel when both the DTE bit and the DTME bit are set to 1. With burst mode setting, the DTME bit is cleared when an NMI interrupt is requested.

If the DTME bit is cleared during burst mode transfer, the DMAC discontinues transfer on completion of the 1-byte or 1-word transfer in progress, then releases the bus, which passes to the CPU.

The channel on which transfer was interrupted can be restarted by setting the DTME bit to 1 again. Figure 7-36 shows the procedure for continuing transfer when it has been interrupted by an NMI interrupt on a channel designated for burst mode transfer.

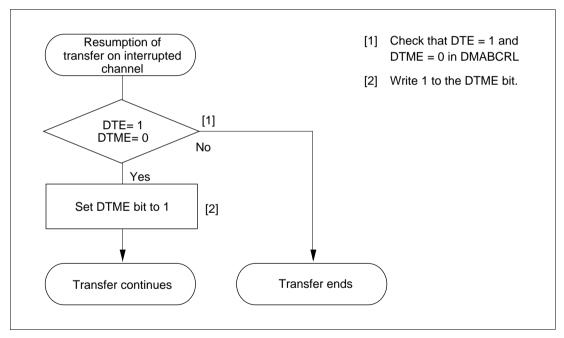


Figure 7-36 Example of Procedure for Continuing Transfer on Channel Interrupted by NMI Interrupt

7.5.16 Forced Termination of DMAC Operation

If the DTE bit for the channel currently operating is cleared to 0, the DMAC stops on completion of the 1-byte or 1-word transfer in progress. DMAC operation resumes when the DTE bit is set to 1 again.

In full address mode, the same applies to the DTME bit.

Figure 7-37 shows the procedure for forcibly terminating DMAC operation by software.

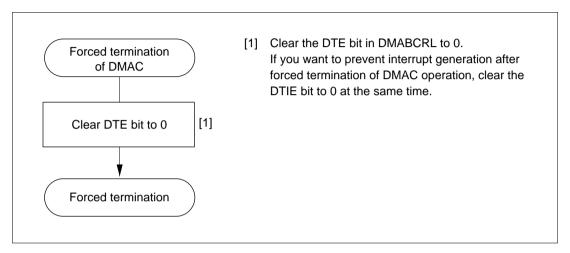


Figure 7-37 Example of Procedure for Forcibly Terminating DMAC Operation

7.5.17 Clearing Full Address Mode

Figure 7-38 shows the procedure for releasing and initializing a channel designated for full address mode. After full address mode has been cleared, the channel can be set to another transfer mode using the appropriate setting procedure.

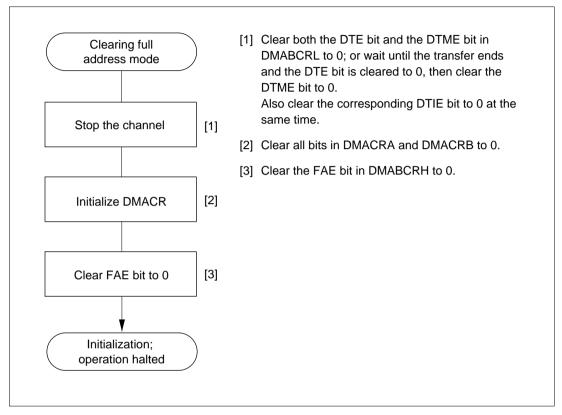


Figure 7-38 Example of Procedure for Clearing Full Address Mode

7.6 Interrupts

The sources of interrupts generated by the DMAC are transfer end and transfer break. Table 7-13 shows the interrupt sources and their priority order.

Table 7-13 Interrupt Source Priority Order

Interrupt	Inte	Interrupt		
Name	Short Address Mode	Priority Order		
DEND0A	Interrupt due to end of transfer on channel 0A	Interrupt due to end of transfer on channel 0	High •	
DEND0B	Interrupt due to end of transfer on channel 0B	Interrupt due to break in transfer on channel 0		
DEND1A	Interrupt due to end of transfer on channel 1A	Interrupt due to end of transfer on channel 1		
DEND1B	Interrupt due to end of transfer on channel 1B	Interrupt due to break in transfer on channel 1	Low	

Enabling or disabling of each interrupt source is set by means of the DTIE bit for the corresponding channel in DMABCR, and interrupts from each source are sent to the interrupt controller independently.

The relative priority of transfer end interrupts on each channel is decided by the interrupt controller, as shown in table 7-13.

Figure 7-39 shows a block diagram of a transfer end/transfer break interrupt. An interrupt is always generated when the DTIE bit is set to 1 while DTE bit is cleared to 0.

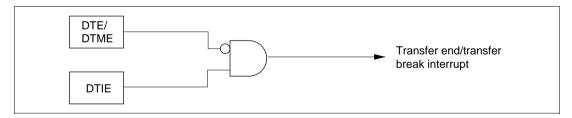


Figure 7-39 Block Diagram of Transfer End/Transfer Break Interrupt

In full address mode, a transfer break interrupt is generated when the DTME bit is cleared to o while DTIEB bit is set to 1.

In both short address mode and full address mode, DMABCR should be set so as to prevent the occurrence of a combination that constitutes a condition for interrupt generation during setting.

7.7 Usage Notes

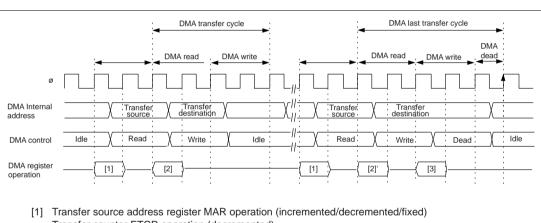
DMAC Register Access during Operation: Except for forced termination, the operating (including transfer waiting state) channel setting should not be changed. The operating channel setting should only be changed when transfer is disabled.

Also, the DMAC register should not be written to in a DMA transfer.

DMAC register reads during operation (including the transfer waiting state) are described below.

(a) DMAC control starts one cycle before the bus cycle, with output of the internal address. Consequently, MAR is updated in the bus cycle before DMAC transfer.

Figure 7-40 shows an example of the update timing for DMAC registers in dual address transfer mode.



- Transfer source address register MAR operation (incremented/decremented/incremented/ Transfer counter ETCR operation (decremented)

 Block size counter ETCR operation (decremented in block transfer mode)
- Block size counter ETCK operation (decremented in block transfer mode)
- [2] Transfer destination address register MAR operation (incremented/decremented/fixed)
- [2'] Transfer destination address register MAR operation (incremented/decremented/fixed) Block transfer counter ETCR operation (decremented, in last transfer cycle of a block in block transfer mode)
- [3] Transfer address register MAR restore operation (in block or repeat transfer mode) Transfer counter ETCR restore (in repeat transfer mode) Block size counter ETCR restore (in block transfer mode)

Notes: 1. In single address transfer mode, the update timing is the same as [1].

2. The MAR operation is post-incrementing/decrementing of the DMA internal address value.

Figure 7-40 Example of DMAC Register Update Timing

(b) DMAC registers are read as shown in Figure 7-41, when the DMAC transfer cycle occurs immediately after the DMAC register has been read.

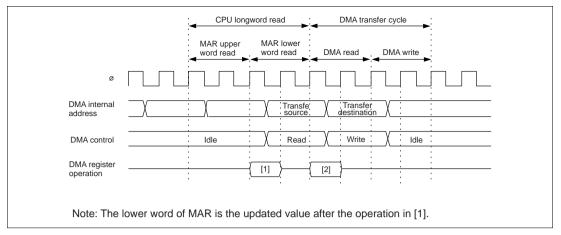


Figure 7-41 Competition between Updating of DMAC Register and CPU Read Operations

Module Stop: When the MSTP15 bit in MSTPCR is set to 1, the DMAC clock stops, and the module stop state is entered. However, 1 cannot be written to the MSTP15 bit if any of the DMAC channels is enabled. This setting should therefore be made when DMAC operation is stopped.

When the DMAC clock stops, DMAC register accesses can no longer be made. Since the following DMAC register settings are valid even in the module stop state, they should be invalidated, if necessary, before a module stop.

- Transfer end/suspend interrupt (DTE = 0 and DTIE = 1)
- $\overline{\text{TEND}}$ pin enable (TEE = 1)
- \overline{DACK} pin enable (FAE = 0 and SAE = 1)

Medium-Speed Mode: When the DTA bit is 0, internal interrupt signals specified as DMAC transfer sources are edge-detected.

In medium-speed mode, the DMAC operates on a medium-speed clock, while on-chip supporting modules operate on a high-speed clock. Consequently, if the period in which the relevant interrupt source is cleared by the CPU, DTC, or another DMAC channel, and the next interrupt is generated, is less than one state with respect to the DMAC clock (bus master clock), edge detection may not be possible and the interrupt may be ignored.

Also, in medium-speed mode, DREQ pin sampling is performed on the rising edge of the medium-speed clock.

Write Data Buffer Function: When the WDBE bit of BCRL in the bus controller is set to 1, enabling the write data buffer function, dual address transfer external write cycles or single address transfers and internal accesses (on-chip memory or internal I/O registers) are executed in parallel.

(a) Write Data Buffer Function and DMAC Register Setting

If the setting of is changed during execution of an external access by means of the write data buffer function, the external access may not be performed normally. The register that controls external accesses should only be manipulated when external reads, etc., are used with DMAC operation disabled, and the operation is not performed in parallel with external access.

(b) Write Data Buffer Function and DMAC Operation Timing

The DMAC can start its next operation during external access using the write data buffer function. Consequently, the \overline{DREQ} pin sampling timing, \overline{TEND} output timing, etc., are different from the case in which the write data buffer function is disabled. Also, internal bus cycles maybe hidden, and not visible.

(c) Write Data Buffer Function and TEND Output

A low level is not output from the \overline{TEND} pin if the bus cycle in which a low level is to be output from the \overline{TEND} pin is an internal bus cycle, and an external write cycle is executed in parallel with this cycle. Note, for example, that a low level may not be output from the \overline{TEND} pin if the write data buffer function is used when data transfer is performed between an internal I/O register and on-chip memory.

If at least one of the DMAC transfer addresses is an external address, a low level is output from the $\overline{\text{TEND}}$ pin.

Figure 7-42 shows an example in which a low level is not output at the $\overline{\text{TEND}}$ pin.

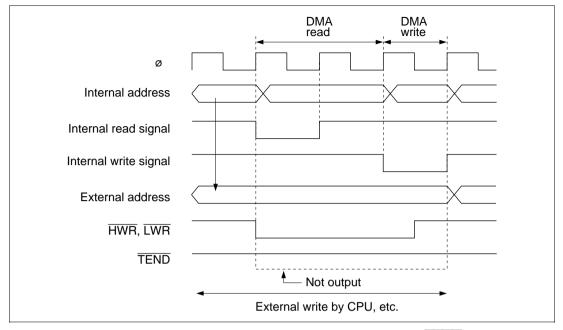


Figure 7-42 Example in Which Low Level is Not Output at TEND Pin

Activation by Falling Edge on \overline{DREQ} Pin: \overline{DREQ} pin falling edge detection is performed in synchronization with DMAC internal operations. The operation is as follows:

- [1] Activation request wait state: Waits for detection of a low level on the \overline{DREQ} pin, and switches to [2].
- [2] Transfer wait state: Waits for DMAC data transfer to become possible, and switches to [3].
- [3] Activation request disabled state: Waits for detection of a high level on the \overline{DREQ} pin, and switches to [1].

After DMAC transfer is enabled, a transition is made to [1]. Thus, initial activation after transfer is enabled is performed by detection of a low level.

Activation Source Acceptance: At the start of activation source acceptance, a low level is detected in both \overline{DREQ} pin falling edge sensing and low level sensing. Similarly, in the case of an internal interrupt, the interrupt request is detected. Therefore, a request is accepted from an internal interrupt or \overline{DREQ} pin low level that occurs before execution of the DMABCRL write to enable transfer.

When the DMAC is activated, take any necessary steps to prevent an internal interrupt or \overline{DREQ} pin low level remaining from the end of the previous transfer, etc.

Internal Interrupt after End of Transfer: When the DTE bit is cleared to 0 by the end of transfer or an abort, the selected internal interrupt request will be sent to the CPU or DTC even if DTA is set to 1.

Also, if internal DMAC activation has already been initiated when operation is aborted, the transfer is executed but flag clearing is not performed for the selected internal interrupt even if DTA is set to 1.

An internal interrupt request following the end of transfer or an abort should be handled by the CPU as necessary.

Channel Re-Setting: To reactivate a number of channels when multiple channels are enabled, use exclusive handling of transfer end interrupts, and perform DMABCR control bit operations exclusively.

Note, in particular, that in cases where multiple interrupts are generated between reading and writing of DMABCR, and a DMABCR operation is performed during new interrupt handling, the DMABCR write data in the original interrupt handling routine will be incorrect, and the write may invalidate the results of the operations by the multiple interrupts. Ensure that overlapping DMABCR operations are not performed by multiple interrupts, and that there is no separation between read and write operations by the use of a bit-manipulation instruction.

Also, when the DTE and DTME bits are cleared by the DMAC or are written with 0, they must first be read while cleared to 0 before the CPU can write a 1 to them.

Section 8 Data Transfer Controller

8.1 Overview

The H8S/2357 Series includes a data transfer controller (DTC). The DTC can be activated by an interrupt or software, to transfer data.

8.1.1 Features

The features of the DTC are:

- Transfer possible over any number of channels
 - Transfer information is stored in memory
 - One activation source can trigger a number of data transfers (chain transfer)
- Wide range of transfer modes
 - Normal, repeat, and block transfer modes available
 - Incrementing, decrementing, and fixing of source and destination addresses can be selected
- Direct specification of 16-Mbyte address space possible
 - 24-bit transfer source and destination addresses can be specified
- Transfer can be set in byte or word units
- A CPU interrupt can be requested for the interrupt that activated the DTC
 - An interrupt request can be issued to the CPU after one data transfer ends
 - An interrupt request can be issued to the CPU after the specified data transfers have completely ended
- Activation by software is possible
- Module stop mode can be set
 - The initial setting enables DTC registers to be accessed. DTC operation is halted by setting module stop mode.

8.1.2 Block Diagram

Figure 8-1 shows a block diagram of the DTC.

The DTC's register information is stored in the on-chip RAM*. A 32-bit bus connects the DTC to the on-chip RAM (1 kbyte), enabling 32-bit/1-state reading and writing of the DTC register information and hence helping to increase processing speed.

Note: * When the DTC is used, the RAME bit in SYSCR must be set to 1.

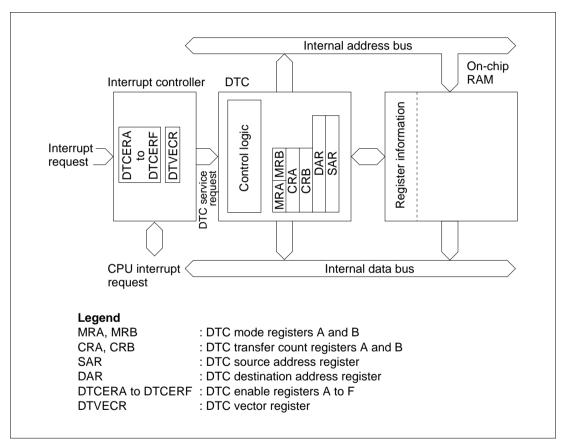


Figure 8-1 Block Diagram of DTC

8.1.3 Register Configuration

Table 8-1 summarizes the DTC registers.

Table 8-1 DTC Registers

Name	Abbreviation	R/W	Initial Value	Address*1
DTC mode register A	MRA	*2	Undefined	*³
DTC mode register B	MRB	<u>_*</u> *2	Undefined	*³
DTC source address register	SAR	<u></u> * ²	Undefined	*³
DTC destination address register	DAR	*2	Undefined	<u>*</u> *3
DTC transfer count register A	CRA	<u>_*</u> *2	Undefined	<u>_*</u> *3
DTC transfer count register B	CRB	<u></u> * ²	Undefined	*³
DTC enable registers	DTCER	R/W	H'00	H'FF30 to H'FF35
DTC vector register	DTVECR	R/W	H'00	H'FF37
Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address.

- 2. Registers within the DTC cannot be read or written to directly.
- 3. Register information is located in on-chip RAM addresses H'F800 to H'FBFF. It cannot be located in external space. When the DTC is used, do not clear the RAME bit in SYSCR to 0.

8.2 Register Descriptions

8.2.1 DTC Mode Register A (MRA)

MRA is an 8-bit register that controls the DTC operating mode.

Bit	:	7	6	5	4	3	2	1	0
		SM1	SM0	DM1	DM0	MD1	MD0	DTS	Sz
Initial val	ue:	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined
R/W	:	_	_	_	_	_	_	_	_

Bits 7 and 6—Source Address Mode 1 and 0 (SM1, SM0): These bits specify whether SAR is to be incremented, decremented, or left fixed after a data transfer.

Bit 7 SM1	Bit 6 SM0	Description
0	_	SAR is fixed
1	0	SAR is incremented after a transfer (by +1 when Sz = 0; by +2 when Sz = 1)
	1	SAR is decremented after a transfer (by -1 when Sz = 0; by -2 when Sz = 1)

Bits 5 and 4—Destination Address Mode 1 and 0 (DM1, DM0): These bits specify whether DAR is to be incremented, decremented, or left fixed after a data transfer.

Bit 5	Bit 4	
DM1	DM0	Description
0	_	DAR is fixed
1	0	DAR is incremented after a transfer (by +1 when Sz = 0; by +2 when Sz = 1)
	1	DAR is decremented after a transfer (by -1 when Sz = 0; by -2 when Sz = 1)

Bits 3 and 2—DTC Mode (MD1, MD0): These bits specify the DTC transfer mode.

Bit 3 MD1	Bit 2 MD0	Description
0	0	Normal mode
	1	Repeat mode
1	0	Block transfer mode
	1	_

Bit 1—DTC Transfer Mode Select (DTS): Specifies whether the source side or the destination side is set to be a repeat area or block area, in repeat mode or block transfer mode.

Bit 1 DTS	Description
0	Destination side is repeat area or block area
1	Source side is repeat area or block area

Bit 0—DTC Data Transfer Size (Sz): Specifies the size of data to be transferred.

Bit 0 Sz	Description
0	Byte-size transfer
1	Word-size transfer

8.2.2 DTC Mode Register B (MRB)

Bit	:	7	6	5	4	3	2	1	0
		CHNE	DISEL		_	_		_	_
Initial value:		Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined
R/W	:	_	_	_	_	_	_		_

MRB is an 8-bit register that controls the DTC operating mode.

Bit 7—DTC Chain Transfer Enable (CHNE): Specifies chain transfer. With chain transfer, a number of data transfers can be performed consecutively in response to a single transfer request.

In data transfer with CHNE set to 1, determination of the end of the specified number of transfers, clearing of the interrupt source flag, and clearing of DTCER is not performed.

Bit 7 CHNE	Description
0	End of DTC data transfer (activation waiting state is entered)
1	DTC chain transfer (new register information is read, then data is transferred)

Bit 6—DTC Interrupt Select (DISEL): Specifies whether interrupt requests to the CPU are disabled or enabled after a data transfer.

Bit 6 DISEL	Description
0	After a data transfer ends, the CPU interrupt is disabled unless the transfer counter is 0 (the DTC clears the interrupt source flag of the activating interrupt to 0)
1	After a data transfer ends, the CPU interrupt is enabled (the DTC does not clear the interrupt source flag of the activating interrupt to 0)

Bits 5 to 0—Reserved: These bits have no effect on DTC operation in the H8S/2357 Series, and should always be written with 0.

8.2.3 DTC Source Address Register (SAR)

Bit	:	23	22	21	20	19	 4	3	2	1	0
Initial value	e :		Unde- fined				 		Unde- fined		Unde- fined
R/W	:	_	_	_	_	_	 _	_	_	_	_

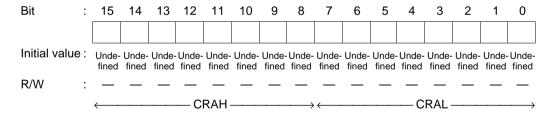
SAR is a 24-bit register that designates the source address of data to be transferred by the DTC. For word-size transfer, specify an even source address.

8.2.4 DTC Destination Address Register (DAR)

Bit	:	23	22	21	20	19	 4	3	2	1	0
Initial value					-Unde- fined		 		Unde- fined		Unde- fined
R/W	:	_	_	_	_	_	 _	_	_	_	

DAR is a 24-bit register that designates the destination address of data to be transferred by the DTC. For word-size transfer, specify an even destination address.

8.2.5 DTC Transfer Count Register A (CRA)



CRA is a 16-bit register that designates the number of times data is to be transferred by the DTC.

In normal mode, the entire CRA functions as a 16-bit transfer counter (1 to 65536). It is decremented by 1 every time data is transferred, and transfer ends when the count reaches H'0000.

In repeat mode or block transfer mode, the CRA is divided into two parts: the upper 8 bits (CRAH) and the lower 8 bits (CRAL). CRAH holds the number of transfers while CRAL functions as an 8-bit transfer counter (1 to 256). CRAL is decremented by 1 every time data is transferred, and the contents of CRAH are sent when the count reaches H'00. This operation is repeated.

8.2.6 DTC Transfer Count Register B (CRB)

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial val	ue:		Unde- fined														
		iiileu	iiiieu	iiileu	iiileu	iiieu	iiiieu	iiileu	iiieu	illieu	illieu	iiileu	illeu	illieu	illieu	illeu	illeu
R/W	:	_	_	_	_	_	_	_	_	_	_	_	_	_	_	_	_

CRB is a 16-bit register that designates the number of times data is to be transferred by the DTC in block transfer mode. It functions as a 16-bit transfer counter (1 to 65536) that is decremented by 1 every time data is transferred, and transfer ends when the count reaches H'0000.

8.2.7 DTC Enable Registers (DTCER)

Bit	Bit : 7		6	5	4	3	2	1	0
		DTCE7	DTCE6	DTCE5	DTCE4	DTCE3	DTCE2	DTCE1	DTCE0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W							

The DTC enable registers comprise six 8-bit readable/writable registers, DTCERA to DTCERF, with bits corresponding to the interrupt sources that can activate the DTC. These bits enable or disable DTC service for the corresponding interrupt sources.

The DTC enable registers are initialized to H'00 by a reset and in hardware standby mode.

Bit n—DTC Activation Enable (DTCEn)

Bit n DTCEn	Description							
0	DTC activation by this interrupt is disabled (Initial value							
	[Clearing conditions]							
	 When the DISEL bit is 1 and the data transfer has ended 							
	When the specified number of transfers have ended							
1	DTC activation by this interrupt is enabled							
	[Holding condition]							
	When the DISEL bit is 0 and the specified number of transfers have not ended							
	(n = 7 to 0							

A DTCE bit can be set for each interrupt source that can activate the DTC. The correspondence between interrupt sources and DTCE bits is shown in table 8-4, together with the vector number generated for each interrupt controller.

For DTCE bit setting, read/write operations must be performed using bit-manipulation instructions such as BSET and BCLR. For the initial setting only, however, when multiple activation sources are set at one time, it is possible to disable interrupts and write after executing a dummy read on the relevant register.

8.2.8 DTC Vector Register (DTVECR)

Bit	: <u>7</u>		6	5	4	3	2	1	0
		SWDTE	DTVEC6	DTVEC5	DTVEC4	DTVEC3	DTVEC2	DTVEC1	DTVEC0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/(W)*	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Note: * A value of 1 can always be written to the SWDTE bit, but 0 can only be written after 1 is read.

DTVECR is an 8-bit readable/writable register that enables or disables DTC activation by software, and sets a vector number for the software activation interrupt.

DTVECR is initialized to H'00 by a reset and in hardware standby mode.

Bit 7—DTC Software Activation Enable (SWDTE): Enables or disables DTC activation by software.

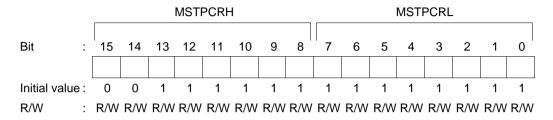
When clearing the SWDTE bit to 0 by software, write 0 to SWDTE after reading SWDTE set to 1.

Bit 7 SWDTE	Description				
0	DTC software activation is disabled	(Initial value)			
	[Clearing condition]				
	When the DISEL bit is 0 and the specified number of transfers have not e	ended			
1	DTC software activation is enabled				
	[Holding conditions]				
	 When the DISEL bit is 1 and data transfer has ended 				
	 When the specified number of transfers have ended 				
	 During data transfer due to software activation 				

Bits 6 to 0—DTC Software Activation Vectors 6 to 0 (DTVEC6 to DTVEC0): These bits specify a vector number for DTC software activation.

The vector address is expressed as H'0400 + ((vector number) << 1). <<1 indicates a one-bit left-shift. For example, when DTVEC6 to DTVEC0 = H'10, the vector address is H'0420.

8.2.9 Module Stop Control Register (MSTPCR)



MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP14 bit in MSTPCR is set to 1, the DTC operation stops at the end of the bus cycle and a transition is made to module stop mode. However, 1 cannot be written in the MSTP14 bit while the DTC is operating. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 14—Module Stop (MSTP14): Specifies the DTC module stop mode.

Bit 14 MSTP14 Description

0	DTC module stop mode cleared	(Initial value)
1	DTC module stop mode set	

8.3 Operation

8.3.1 Overview

When activated, the DTC reads register information that is already stored in memory and transfers data on the basis of that register information. After the data transfer, it writes updated register information back to memory. Pre-storage of register information in memory makes it possible to transfer data over any required number of channels. Setting the CHNE bit to 1 makes it possible to perform a number of transfers with a single activation.

Figure 8-2 shows a flowchart of DTC operation.

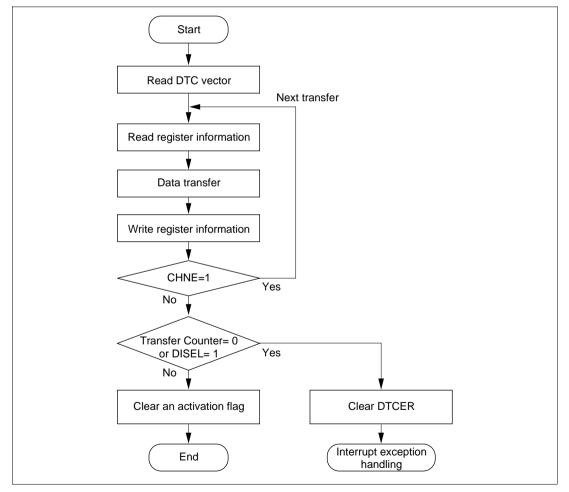


Figure 8-2 Flowchart of DTC Operation

The DTC transfer mode can be normal mode, repeat mode, or block transfer mode.

The 24-bit SAR designates the DTC transfer source address and the 24-bit DAR designates the transfer destination address. After each transfer, SAR and DAR are independently incremented, decremented, or left fixed.

Table 8-2 outlines the functions of the DTC.

Table 8-2 DTC Functions

				Addres	s Registers
Tr	ansfer Mode	Ad	ctivation Source		Transfer Destination
•	Normal mode	•	IRQ	24 bits	24 bits
	 One transfer request transfers one byte or one 	•	TPU TGI		
	word	•	8-bit timer CMI		
	 Memory addresses are incremented or 	•	SCI TXI or RXI		
	decremented by 1 or 2	•	A/D converter		
	 Up to 65,536 transfers possible 		ADI		
•	Repeat mode	•	DMAC DEND		
	 One transfer request transfers one byte or one word 	•	Software		
	 Memory addresses are incremented or decremented by 1 or 2 				
	 After the specified number of transfers (1 to 256), the initial state resumes and operation continues 				
•	Block transfer mode				
	 One transfer request transfers a block of the specified size 				
	 Block size is from 1 to 256 bytes or words 				
	— Up to 65,536 transfers possible				
	 A block area can be designated at either the source or destination 				

8.3.2 Activation Sources

The DTC operates when activated by an interrupt or by a write to DTVECR by software. An interrupt request can be directed to the CPU or DTC, as designated by the corresponding DTCER bit. An interrupt becomes a DTC activation source when the corresponding bit is set to 1, and a CPU interrupt source when the bit is cleared to 0.

At the end of a data transfer (or the last consecutive transfer in the case of chain transfer), the activation source or corresponding DTCER bit is cleared. Table 8-3 shows activation source and DTCER clearance. The activation source flag, in the case of RXIO, for example, is the RDRF flag of SCIO.

Table 8-3 Activation Source and DTCER Clearance

Activation Source	When the DISEL Bit Is 0 and the Specified Number of Transfers Have Not Ended	When the DISEL Bit Is 1, or when the Specified Number of Transfers Have Ended
Software activation	The SWDTE bit is cleared to 0	The SWDTE bit remains set to 1
		An interrupt is issued to the CPU
Interrupt activation	The corresponding DTCER bit remains set to 1	The corresponding DTCER bit is cleared to 0
	The activation source flag is	The activation source flag remains set to 1
	cleared to 0	A request is issued to the CPU for the activation source interrupt

Figure 8-3 shows a block diagram of activation source control. For details see section 5, Interrupt Controller.

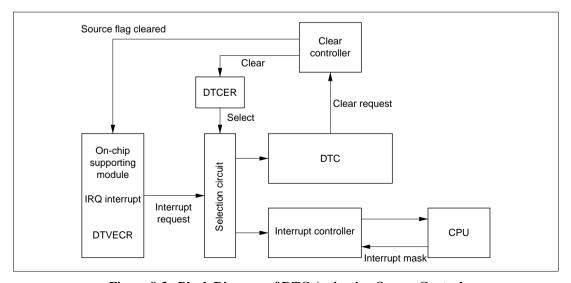


Figure 8-3 Block Diagram of DTC Activation Source Control

When an interrupt has been designated a DTC activation source, existing CPU mask level and interrupt controller priorities have no effect. If there is more than one activation source at the same time, the DTC operates in accordance with the default priorities.

8.3.3 DTC Vector Table

Figure 8-4 shows the correspondence between DTC vector addresses and register information.

Table 8-4 shows the correspondence between activation, vector addresses, and DTCER bits. When the DTC is activated by software, the vector address is obtained from: H'0400 + (DTVECR[6:0] << 1) (where << 1 indicates a 1-bit left shift). For example, if DTVECR is H'10, the vector address is H'0420.

The DTC reads the start address of the register information from the vector address set for each activation source, and then reads the register information from that start address. The register information can be placed at predetermined addresses in the on-chip RAM. The start address of the register information should be an integral multiple of four.

The configuration of the vector address is the same in both normal and advanced modes, a 2-byte unit being used in both cases. These two bytes specify the lower bits of the address in the on-chip RAM.

Table 8-4 Interrupt Sources, DTC Vector Addresses, and Corresponding DTCEs

Interrupt Source	Origin of Interrupt Source	Vector Number	Vector Address	DTCE*	Priority
Write to DTVECR	Software	DTVECR	H'0400+ (DTVECR [6:0]<<1)	_	High A
IRQ0	External pin	16	H'0420	DTCEA7	_
IRQ1		17	H'0422	DTCEA6	_
IRQ2		18	H'0424	DTCEA5	_
IRQ3		19	H'0426	DTCEA4	_
IRQ4		20	H'0428	DTCEA3	_
IRQ5		21	H'042A	DTCEA2	_
IRQ6		22	H'042C	DTCEA1	_
IRQ7		23	H'042E	DTCEA0	_
ADI (A/D conversion end)	A/D	28	H'0438	DTCEB6	_
TGI0A (GR0A compare match/input capture)	TPU channel 0	32	H'0440	DTCEB5	
TGI0B (GR0B compare match/ input capture)		33	H'0442	DTCEB4	
TGI0C (GR0C compare match/input capture)		34	H'0444	DTCEB3	
TGI0D (GR0D compare match/ input capture)		35	H'0446	DTCEB2	
TGI1A (GR1A compare match/input capture)	TPU channel 1	40	H'0450	DTCEB1	
TGI1B (GR1B compare match/input capture)		41	H'0452	DTCEB0	
TGI2A (GR2A compare match/input capture)	TPU channel 2	44	H'0458	DTCEC7	
TGI2B (GR2B compare match/input capture)		45	H'045A	DTCEC6	Low

Intermed Course	Origin of Interrupt	Vector	Vector	DT0E*	Dulantu
Interrupt Source	Source	Number	Address	DTCE*	Priority
TGI3A (GR3A compare match/input capture)	TPU channel 3	48	H'0460	DTCEC5	High ≜
TGI3B (GR3B compare match/input capture)		49	H'0462	DTCEC4	
TGI3C (GR3C compare match/input capture)	_	50	H'0464	DTCEC3	
TGI3D (GR3D compare match/input capture)	_	51	H'0466	DTCEC2	
TGI4A (GR4A compare match/ input capture)	TPU channel 4	56	H'0470	DTCEC1	
TGI4B (GR4B compare match/ input capture)	_	57	H'0472	DTCEC0	
TGI5A (GR5A compare match/input capture)	TPU channel 5	60	H'0478	DTCED5	
TGI5B (GR5B compare match/input capture)	_	61	H'047A	DTCED4	
CMIA0	8-bit timer	64	H'0480	DTCED3	_
CMIB0	channel 0	65	H'0482	DTCED2	_
CMIA1	8-bit timer	68	H'0488	DTCED1	_
CMIB1	channel 1	69	H'048A	DTCED0	_
DMTEND0A (DMAC transfer end 0)) DMAC	72	H'0490	DTCEE7	_
DMTEND0B (DMAC transfer end 1)	<u> </u>	73	H'0492	DTCEE6	_
DMTEND1A (DMAC transfer end 2)		74	H'0494	DTCEE5	_
DMTEND1B (DMAC transfer end 3)		75	H'0496	DTCEE4	_
RXI0 (reception data full 0)	SCI	81	H'04A2	DTCEE3	_
TXI0 (transmit data empty 0)	channel 0	82	H'04A4	DTCEE2	
RXI1 (reception data full 1)	SCI	85	H'04AA	DTCEE1	
TXI1 (transmit data empty 1)	channel 1	86	H'04AC	DTCEE0	
RXI2 (reception data full 2)	SCI	89	H'04B2	DTCEF7	
TXI2 (transmit data empty 2)	channel 2	90	H'04B4	DTCEF6	Low

Note: * DTCE bits with no corresponding interrupt are reserved, and should be written with 0.

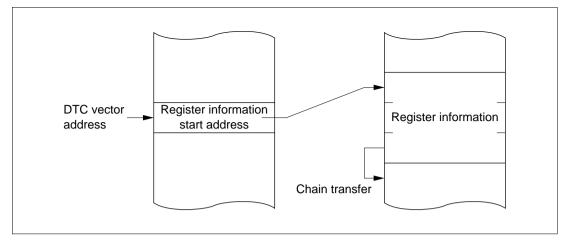


Figure 8-4 Correspondence between DTC Vector Address and Register Information

8.3.4 Location of Register Information in Address Space

Figure 8-5 shows how the register information should be located in the address space.

Locate the MRA, SAR, MRB, DAR, CRA, and CRB registers, in that order, from the start address of the register information (contents of the vector address). In the case of chain transfer, register information should be located in consecutive areas.

Locate the register information in the on-chip RAM (addresses: H'FFF800 to H'FFFBFF).

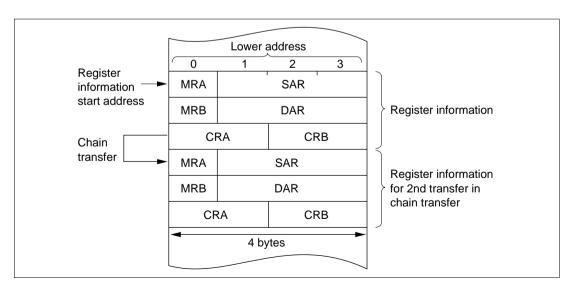


Figure 8-5 Location of Register Information in Address Space

8.3.5 Normal Mode

In normal mode, one operation transfers one byte or one word of data.

From 1 to 65,536 transfers can be specified. Once the specified number of transfers have ended, a CPU interrupt can be requested.

Table 8-5 lists the register information in normal mode and figure 8-6 shows memory mapping in normal mode.

Table 8-5 Register Information in Normal Mode

Name	Abbreviation	Function
DTC source address register	SAR	Designates source address
DTC destination address register	DAR	Designates destination address
DTC transfer count register A	CRA	Designates transfer count
DTC transfer count register B	CRB	Not used

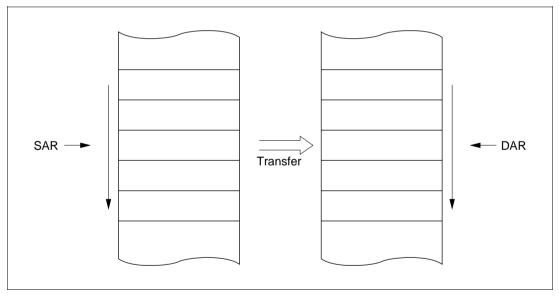


Figure 8-6 Memory Mapping in Normal Mode

8.3.6 Repeat Mode

In repeat mode, one operation transfers one byte or one word of data.

From 1 to 256 transfers can be specified. Once the specified number of transfers have ended, the initial state of the transfer counter and the address register specified as the repeat area is restored, and transfer is repeated. In repeat mode the transfer counter value does not reach H'00, and therefore CPU interrupts cannot be requested when DISEL = 0.

Table 8-6 lists the register information in repeat mode and figure 8-7 shows memory mapping in repeat mode.

Table 8-6 Register Information in Repeat Mode

Name	Abbreviation	Function
DTC source address register	SAR	Designates source address
DTC destination address register	DAR	Designates destination address
DTC transfer count register AH	CRAH	Holds number of transfers
DTC transfer count register AL	CRAL	Designates transfer count (8 bits \times 2)
DTC transfer count register B	CRB	Not used

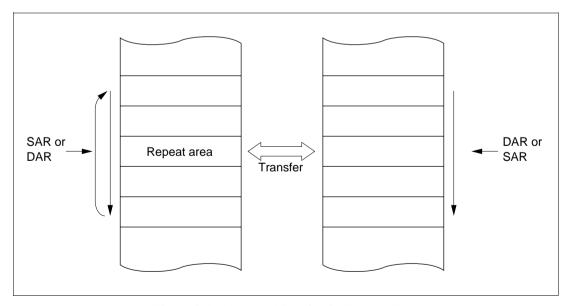


Figure 8-7 Memory Mapping in Repeat Mode

8.3.7 Block Transfer Mode

In block transfer mode, one operation transfers one block of data.

The block size is 1 to 256. When the transfer of one block ends, the initial state of the block size counter and the address register specified as the block area is restored. The other address register is then incremented, decremented, or left fixed.

From 1 to 65,536 transfers can be specified. Once the specified number of transfers have ended, a CPU interrupt is requested.

Table 8-7 lists the register information in block transfer mode and figure 8-8 shows memory mapping in block transfer mode.

Table 8-7 Register Information in Block Transfer Mode

Name	Abbreviation	Function
DTC source address register	SAR	Designates transfer source address
DTC destination address register	DAR	Designates destination address
DTC transfer count register AH	CRAH	Holds block size
DTC transfer count register AL	CRAL	Designates block size count
DTC transfer count register B	CRB	Transfer count

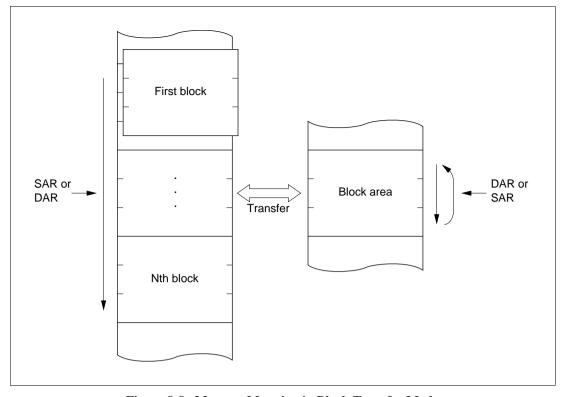


Figure 8-8 Memory Mapping in Block Transfer Mode

8.3.8 Chain Transfer

Setting the CHNE bit to 1 enables a number of data transfers to be performed consectutively in response to a single transfer request. SAR, DAR, CRA, CRB, MRA, and MRB, which define data transfers, can be set independently.

Figure 8-9 shows the memory map for chain transfer.

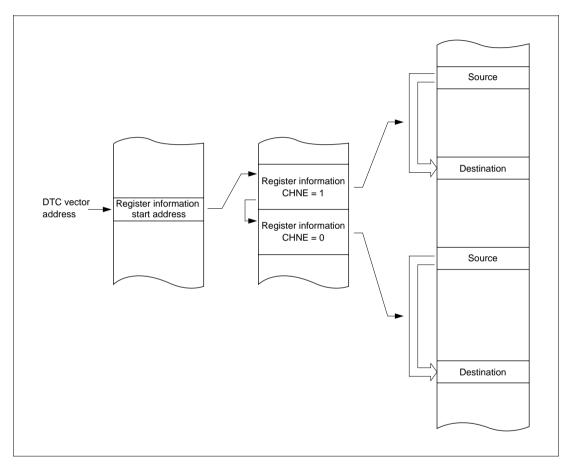


Figure 8-9 Chain Transfer Memory Map

In the case of transfer with CHNE set to 1, an interrupt request to the CPU is not generated at the end of the specified number of transfers or by setting of the DISEL bit to 1, and the interrupt source flag for the activation source is not affected.

8.3.9 Operation Timing

Figures 8-10 to 8-12 show an example of DTC operation timing.

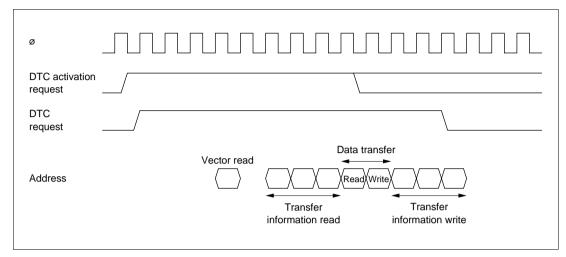


Figure 8-10 DTC Operation Timing (Example in Normal Mode or Repeat Mode)

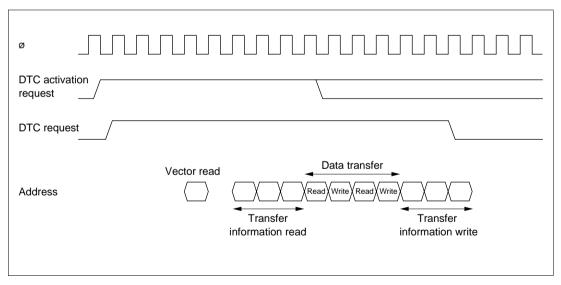


Figure 8-11 DTC Operation Timing (Example of Block Transfer Mode, with Block Size of 2)

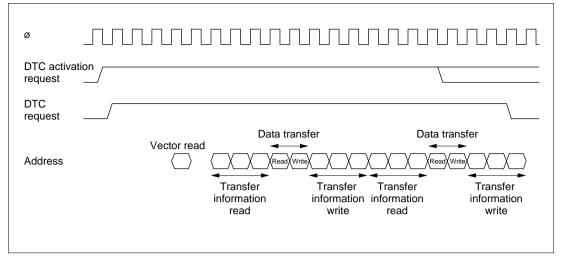


Figure 8-12 DTC Operation Timing (Example of Chain Transfer)

8.3.10 Number of DTC Execution States

Table 8-8 lists execution statuses for a single DTC data transfer, and table 8-9 shows the number of states required for each execution status.

Table 8-8 DTC Execution Statuses

Mode	Vector Read I	Register Information Read/Write J	Data Read K	Data Write L	Internal Operations M
Normal	1	6	1	1	3
Repeat	1	6	1	1	3
Block transfer	1	6	N	N	3

N: Block size (initial setting of CRAH and CRAL)

Table 8-9 Number of States Required for Each Execution Status

Object to k	On- Chip RAM	On- Chip ROM	On-Cl Regis	hip I/O sters	Exteri	nal Devi	ces			
Bus width			32	16	8	16	8		16	
Access sta	tes		1	1	2	2	2	3	2	3
Execution	Vector read	Sı	_	1	_	_	4	6+2m	2	3+m
status	Register information read/write	S _J	1	_	_	_	_	_	_	_
	Byte data read	S _K	1	1	2	2	2	3+m	2	3+m
	Word data read	Sĸ	1	1	4	2	4	6+2m	2	3+m
	Byte data write	S _L	1	1	2	2	2	3+m	2	3+m
	Word data write	S _L	1	1	4	2	4	6+2m	2	3+m
	Internal operation	$S_{\scriptscriptstyle M}$	1							

The number of execution states is calculated from the formula below. Note that Σ means the sum of all transfers activated by one activation event (the number in which the CHNE bit is set to 1, plus 1).

Number of execution states =
$$I \cdot S_I + \Sigma (J \cdot S_I + K \cdot S_K + L \cdot S_L) + M \cdot S_M$$

For example, when the DTC vector address table is located in on-chip ROM, normal mode is set, and data is transferred from the on-chip ROM to an internal I/O register, the time required for the DTC operation is 13 states. The time from activation to the end of the data write is 10 states.

8.3.11 Procedures for Using DTC

Activation by Interrupt: The procedure for using the DTC with interrupt activation is as follows:

- [1] Set the MRA, MRB, SAR, DAR, CRA, and CRB register information in the on-chip RAM.
- [2] Set the start address of the register information in the DTC vector address.
- [3] Set the corresponding bit in DTCER to 1.
- [4] Set the enable bits for the interrupt sources to be used as the activation sources to 1. The DTC is activated when an interrupt used as an activation source is generated.
- [5] After the end of one data transfer, or after the specified number of data transfers have ended, the DTCE bit is cleared to 0 and a CPU interrupt is requested. If the DTC is to continue transferring data, set the DTCE bit to 1.

Activation by Software: The procedure for using the DTC with software activation is as follows:

- [1] Set the MRA, MRB, SAR, DAR, CRA, and CRB register information in the on-chip RAM.
- [2] Set the start address of the register information in the DTC vector address.
- [3] Check that the SWDTE bit is 0.
- [4] Write 1 to SWDTE bit and the vector number to DTVECR.
- [5] Check the vector number written to DTVECR.
- [6] After the end of one data transfer, if the DISEL bit is 0 and a CPU interrupt is not requested, the SWDTE bit is cleared to 0. If the DTC is to continue transferring data, set the SWDTE bit to 1. When the DISEL bit is 1, or after the specified number of data transfers have ended, the SWDTE bit is held at 1 and a CPU interrupt is requested.

8.3.12 Examples of Use of the DTC

(1) Normal Mode

An example is shown in which the DTC is used to receive 128 bytes of data via the SCI.

- [1] Set MRA to fixed source address (SM1 = SM0 = 0), incrementing destination address (DM1 = 1, DM0 = 0), normal mode (MD1 = MD0 = 0), and byte size (Sz = 0). The DTS bit can have any value. Set MRB for one data transfer by one interrupt (CHNE = 0, DISEL = 0). Set the SCI RDR address in SAR, the start address of the RAM area where the data will be received in DAR, and 128 (H'0080) in CRA. CRB can be set to any value.
- [2] Set the start address of the register information at the DTC vector address.
- [3] Set the corresponding bit in DTCER to 1.
- [4] Set the SCI to the appropriate receive mode. Set the RIE bit in SCR to 1 to enable the reception complete (RXI) interrupt. Since the generation of a receive error during the SCI reception operation will disable subsequent reception, the CPU should be enabled to accept receive error interrupts.
- [5] Each time reception of one byte of data ends on the SCI, the RDRF flag in SSR is set to 1, an RXI interrupt is generated, and the DTC is activated. The receive data is transferred from RDR to RAM by the DTC. DAR is incremented and CRA is decremented. The RDRF flag is automatically cleared to 0.
- [6] When CRA becomes 0 after the 128 data transfers have ended, the RDRF flag is held at 1, the DTCE bit is cleared to 0, and an RXI interrupt request is sent to the CPU. The interrupt handling routine should perform wrap-up processing.

(2) Chain Transfer

An example of DTC chain transfer is shown in which pulse output is performed using the PPG. Chain transfer can be used to perform pulse output data transfer and PPG output trigger cycle updating. Repeat mode transfer to the PPG's NDR is performed in the first half of the chain transfer, and normal mode transfer to the TPU's TGR in the second half. This is because clearing of the activation source and interrupt generation at the end of the specified number of transfers are restricted to the second half of the chain transfer (transfer when CHNE = 0).

[1] Perform settings for transfer to the PPG's NDR. Set MRA to source address incrementing (SM1 = 1, SM0 = 0), fixed destination address (DM1 = DM0 = 0), repeat mode (MD1 = 0, MD0 = 1), and word size (Sz = 1). Set the source side as a repeat area (DTS = 1). Set MRB to chain mode (CHNE = 1, DISEL = 0). Set the data table start address in SAR, the NDRH address in DAR, and the data table size in CRAH and CRAL. CRB can be set to any value.

- [2] Perform settings for transfer to the TPU's TGR. Set MRA to source address incrementing (SM1 = 1, SM0 = 0), fixed destination address (DM1 = DM0 = 0), normal mode (MD1 = MD0 = 0), and word size (Sz = 1). Set the data table start address in SAR, the TGRA address in DAR, and the data table size in CRA. CRB can be set to any value.
- [3] Locate the TPU transfer register information consecutively after the NDR transfer register information.
- [4] Set the start address of the NDR transfer register information to the DTC vector address.
- [5] Set the bit corresponding to TGIA in DTCER to 1.
- [6] Set TGRA as an output compare register (output disabled) with TIOR, and enable the TGIA interrupt with TIER.
- [7] Set the initial output value in PODR, and the next output value in NDR. Set bits in DDR and NDER for which output is to be performed to 1. Using PCR, select the TPU compare match to be used as the output trigger.
- [8] Set the CST bit in TSTR to 1, and start the TCNT count operation.
- [9] Each time a TGRA compare match occurs, the next output value is transferred to NDR and the set value of the next output trigger period is transferred to TGRA. The activation source TGFA flag is cleared.
- [10] When the specified number of transfers are completed (the TPU transfer CRA value is 0), the TGFA flag is held at 1, the DTCE bit is cleared to 0, and a TGIA interrupt request is sent to the CPU. Termination processing should be performed in the interrupt handling routine.

(3) Software Activation

An example is shown in which the DTC is used to transfer a block of 128 bytes of data by means of software activation. The transfer source address is H'1000 and the destination address is H'2000. The vector number is H'60, so the vector address is H'04C0.

- [1] Set MRA to incrementing source address (SM1 = 1, SM0 = 0), incrementing destination address (DM1 = 1, DM0 = 0), block transfer mode (MD1 = 1, MD0 = 0), and byte size (Sz = 0). The DTS bit can have any value. Set MRB for one block transfer by one interrupt (CHNE = 0). Set the transfer source address (H'1000) in SAR, the destination address (H'2000) in DAR, and 128 (H'8080) in CRA. Set 1 (H'0001) in CRB.
- [2] Set the start address of the register information at the DTC vector address (H'04C0).

- [3] Check that the SWDTE bit in DTVECR is 0. Check that there is currently no transfer activated by software.
- [4] Write 1 to the SWDTE bit and the vector number (H'60) to DTVECR. The write data is H'E0.
- [5] Read DTVECR again and check that it is set to the vector number (H'60). If it is not, this indicates that the write failed. This is presumably because an interrupt occurred between steps 3 and 4 and led to a different software activation. To activate this transfer, go back to step 3.
- [6] If the write was successful, the DTC is activated and a block of 128 bytes of data is transferred.
- [7] After the transfer, an SWDTEND interrupt occurs. The interrupt handling routine should clear the SWDTE bit to 0 and perform other wrap-up processing.

8.4 Interrupts

An interrupt request is issued to the CPU when the DTC finishes the specified number of data transfers, or a data transfer for which the DISEL bit was set to 1. In the case of interrupt activation, the interrupt set as the activation source is generated. These interrupts to the CPU are subject to CPU mask level and interrupt controller priority level control.

In the case of activation by software, a software activated data transfer end interrupt (SWDTEND) is generated.

When the DISEL bit is 1 and one data transfer has ended, or the specified number of transfers have ended, after data transfer ends, the SWDTE bit is held at 1 and an SWDTEND interrupt is generated. The interrupt handling routine should clear the SWDTE bit to 0.

When the DTC is activated by software, an SWDTEND interrupt is not generated during a data transfer wait or during data transfer even if the SWDTE bit is set to 1.

8.5 Usage Notes

Module Stop: When the MSTP14 bit in MSTPCR is set to 1, the DTC clock stops, and the DTC enters the module stop state. However, 1 cannot be written in the MSTP14 bit while the DTC is operating.

On-Chip RAM: The MRA, MRB, SAR, DAR, CRA, and CRB registers are all located in on-chip RAM. When the DTC is used, the RAME bit in SYSCR must not be cleared to 0.

DMAC Transfer End Interrupt: When DTC transfer is activated by a DMAC transfer end interrupt, regardless of the transfer counter and DISEL bit, the DMAC's DTE bit is not subject to DTC control, and the write data has priority. Consequently, an interrupt request may not be sent to the CPU when the DTC transfer counter reaches 0.

DTCE Bit Setting: For DTCE bit setting, read/write operations must be performed using bit-manipulation instructions such as BSET and BCLR. For the initial setting only, however, when multiple activation sources are set at one time, it is possible to disable interrupts and write after executing a dummy read on the relevant register.

Section 9 I/O Ports

9.1 Overview

The H8S/2357 Series has 12 I/O ports (ports 1, 2, 3, 5, 6, and A to G), and one input-only port (port 4).

Table 9-1 summarizes the port functions. The pins of each port also have other functions.

Each port includes a data direction register (DDR) that controls input/output (not provided for the input-only port), a data register (DR) that stores output data, and a port register (PORT) used to read the pin states.

Ports A to E have a built-in pull-up MOS function, and in addition to DR and DDR, have a MOS input pull-up control register (PCR) to control the on/off state of MOS input pull-up.

Port 3 and port A include an open-drain control register (ODR) that controls the on/off state of the output buffer PMOS.

Ports 1, and A to F can drive a single TTL load and 90 pF capacitive load, and ports 2, 3, 5, 6, and G can drive a single TTL load and 30 pF capacitive load. All the I/O ports can drive a Darlington transistor when in output mode. Ports 1, A, B, and C can drive an LED (10 mA sink current).

Port 2, and pins 6_4 to 6_7 and A_4 to A_7 , are Schmitt-triggered inputs.

For block diagrams of the ports see appendix C, I/O Port Block Diagrams.

Table 9-1 Port Functions

Port	Description	Pins	Mode 4*3	Mode 5*3	Mode 6	Mode 7	
Port 1	8-bit I/O port	P1 ₇ /PO15/TIOCB2/TCLKD P1 ₆ /PO14/TIOCA2 P1 ₅ /PO13/TIOCB1/TCLKC P1 ₄ /PO12/TIOCA1 P1 ₃ /PO11/TIOCD0/TCLKB P1 ₂ /PO10/TIOCC0/TCLKA P1 ₁ /PO9/TIOCB0/DACK1 P1 ₀ /PO8/TIOCA0/DACK0	(DACKO and DACK1), TPU I/O pins (TCLKA, TCLKB, TCLKC, TCLKD, TIOCA0, TIOCB0, TIOCC0, TIOCD0, TIOCA1, TIOCB1, TIOCA2, TIOCB2) and PPG output pin (PO15 to PO8)				
Port 2	8-bit I/O port Schmitt-triggered input	P2 ₇ /PO7/TIOCB5/TMO1 P2 ₆ /PO6/TIOCA5/TMO0 P2 ₅ /PO5/TIOCB4/TMCI1 P2 ₄ /PO4/TIOCA4/TMRI1 P2 ₃ /PO3/TIOCD3/TMCI0 P2 ₂ /PO2/TIOCC3/TMRI0 P2 ₁ /PO1/TIOCB3 P2 ₀ /PO0/TIOCA3	8-bit I/O port al TIOCB3, TIOC TIOCB5), 8-bit TMCI0, TMO0, (PO7 to PO0)	C3, TIOCD3, T timer (channels	IOCA4, TIOCB s 0 and 1) I/O p	4, TIOCA5, ins (TMRI0,	
Port 3	6-bit I/O port Open-drain output capability	P3 ₅ /SCK1 P3 ₄ /SCK0 P3 ₃ /RxD1 P3 ₂ /RxD0 P3 ₁ /TxD1 P3 ₀ /TxD0	6-bit I/O port al pins (TxD0, Rx				
Port 4	8-bit input port	P4 ₇ /AN7/DA1 P4 ₆ /AN6/DA0 P4 ₅ /AN5 P4 ₄ /AN4 P4 ₃ /AN3 P4 ₂ /AN2 P4 ₁ /AN1 P4 ₀ /AN0	8-bit input port inputs (AN7 to and DA0)				
Port 5	• 4-bit I/O port	P5 ₃ /ADTRG P5 ₂ /SCK2 P5 ₁ /RxD2 P5 ₀ /TxD2	4-bit I/O port al (TxD2, RxD2, \$				

Port	Description	Pins	Mode 4*3	Mode 5*3	Mode 6	Mode 7
Port 6	 8-bit I/O port Schmitt-triggered input (P6₄ to P6₇) 	P6 ₇ /IRQ3/CS7 P6 ₆ /IRQ2/CS6 P6 ₅ /IRQ1 P6 ₄ /IRQ0 P6 ₃ /TEND1 P6 ₂ /DREQ1 P6 ₁ /TEND0/CS5 P6 ₀ /DREQ0/CS4	8-bit I/O port als controller I/O pi DREQ1, TEND (CS4 to CS7), a to IRQ3)	ns (DREQ0, T 1), bus control	END0, output pins	8-bit I/O port also function- ing as inter- rupt input pins (IRQ0 to IRQ3)
Port A	8-bit I/O port Built-in MOS input pull-up*4 Open-drain output capability*4 Schmitt-triggered input (RA + CRA)	$\begin{aligned} &PA_{7} /A_{23} \overline{/IRQ7} \\ &PA_{6} /A_{22} \overline{/IRQ6} \\ &PA_{5} /A_{21} \overline{/IRQ5} \end{aligned}$ $&PA_{4} /A_{20} \overline{/IRQ4}$	When DDR = 0 dual function as and interrupt in to IRQ5) When DDR = 1 output Address output	s input ports put pins (IRQ7 : address	When DDR = 0 (after reset): dual function as input ports and interrupt input pins (IRQ7 to IRQ4) When DDR = 1: address output	Dual function as I/O ports and interrupt input pins (IRQ7 to IRQ4)
	(PA ₄ to PA ₇)	PA ₃ /A ₁₉ to PA ₀ /A ₁₆	Address output		When DDR = 0 (after reset): input ports When DDR = 1: address output	I/O ports
Port B	8-bit I/O port Built-in MOS input pull-up*4	PB ₇ /A ₁₅ to PB ₀ /A ₈	Address output		When DDR = 0 (after reset): input port When DDR = 1: address output	I/O port
Port C	8-bit I/O port Built-in MOS input pull-up*4	PC ₇ /A ₇ to PC ₀ /A ₀	Address output		When DDR = 0 (after reset): input port When DDR = 1: address output	I/O port
Port D	 8-bit I/O port Built-in MOS input pull-up*4 	PD ₇ /D ₁₅ to PD ₀ /D ₈	Data bus input/	output		I/O port

Port	Description	Pins	Mode 4*3	Mode 5*3	Mode 6	Mode 7
Port E	8-bit I/O port Built-in MOS input pull-up*4	PE_7/D_7 to PE_0/D_0	In 8-bit bus mo In 16-bit bus m	de: I/O port ode: data bus ii	nput/output	I/O port
Port F	• 8-bit I/O port	PF ₇ /Ø	When DDR = 0 When DDR = 1	When DDR = 0 (after reset): input port When DDR = 1: Ø output		
		PF ₆ /ĀS PF ₅ /RD PF ₄ /HWR PF ₃ /LWR	AS, RD, HWR,	LWR output		I/O port
		PF ₂ /LCAS/WAIT/BREQO	reset): I/O port	= 0 and BREQC = 1 and BREQC	,	
			•	= 0 and BREQC	DE = 1:	
				to RMTS0= B'0 .CASS= 0: LCA	′	
		PF₁/BACK PF₀/BREQ		0 (after reset): I 1: BREQ input,	•	
Port G	• 5-bit I/O port	PG ₄ /CS0	When DDR = 0 When DDR = 1)*1: input port *2: CSO output		I/O port
		PG ₃ /CS1 PG ₂ /CS2 PG ₁ /CS3		(after reset): ir		
		PG ₀ /CAS	-	et: CAS output er reset): I/O po		

Notes: 1. After a reset in mode 6

- 2. After a reset in mode 4 or 5
- 3. In ROMless version, only modes 4 and 5 are available.
- 4. Applies to the on-chip ROM version only.

9.2 Port 1

9.2.1 Overview

Port 1 is an 8-bit I/O port. Port 1 pins also function as PPG output pins (PO15 to PO8), TPU I/O pins (TCLKA, TCLKB, TCLKC, TCLKD, TIOCA0, TIOCB0, TIOCC0, TIOCD0, TIOCA1, TIOCB1, TIOCA2, and TIOCB2), and DMAC output pins (DACK0 and DACK1). Port 1 pin functions are the same in all operating modes.

Figure 9-1 shows the port 1 pin configuration.

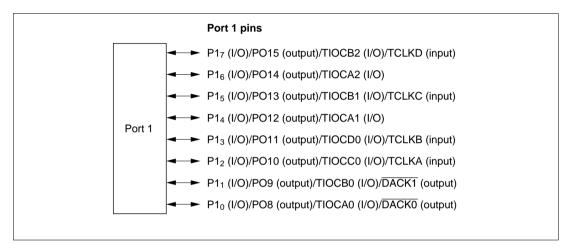


Figure 9-1 Port 1 Pin Functions

9.2.2 Register Configuration

Table 9-2 shows the port 1 register configuration.

Table 9-2 Port 1 Registers

Name	Abbreviation	R/W	Initial Value	Address*
Port 1 data direction register	P1DDR	W	H'00	H'FEB0
Port 1 data register	P1DR	R/W	H'00	H'FF60
Port 1 register	PORT1	R	Undefined	H'FF50

Note: * Lower 16 bits of the address.

Port 1 Data Direction Register (P1DDR)

Bit	:	7	6	5	4	3	2	1	0
		P17DDR	P16DDR	P15DDR	P14DDR	P13DDR	P12DDR	P11DDR	P10DDR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

P1DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 1. P1DDR cannot be read; if it is, an undefined value will be read.

Setting a P1DDR bit to 1 makes the corresponding port 1 pin an output pin, while clearing the bit to 0 makes the pin an input pin.

P1DDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. As the PPG, TPU, and DMAC are initialized by a manual reset*, the pin states are determined by the P1DDR and P1DR specifications.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 1 Data Register (P1DR)

Bit	:	7	6	5	4	3	2	1	0
		P17DR	P16DR	P15DR	P14DR	P13DR	P12DR	P11DR	P10DR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

P1DR is an 8-bit readable/writable register that stores output data for the port 1 pins (P1₇ to P1₀).

P1DR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 1 Register (PORT1)

Bit	:	7	6	5	4	3	2	1	0
		P17	P16	P15	P14	P13	P12	P11	P10
Initial val	ue:	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins P1, to P1,.

PORT1 is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port 1 pins ($P1_7$ to $P1_0$) must always be performed on P1DR.

If a port 1 read is performed while P1DDR bits are set to 1, the P1DR values are read. If a port 1 read is performed while P1DDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORT1 contents are determined by the pin states, as P1DDR and P1DR are initialized. PORT1 retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

9.2.3 Pin Functions

Port 1 pins also function as PPG output pins (PO15 to PO8), TPU I/O pins (TCLKA, TCLKB, TCLKC, TCLKD, TIOCA0, TIOCB0, TIOCC0, TIOCD0, TIOCA1, TIOCB1, TIOCA2, and TIOCB2), and DMAC output pins (DACK0 and DACK1). Port 1 pin functions are shown in table 9-3.

Table 9-3 Port 1 Pin Functions

Pin Selection Method and Pin Functions

P1₇/PO15/TIOCB2/ The pin function is switched as shown below according to the combination of TCLKD the TPU channel 2 setting by bits MD3 to MD0 in TMDR2, bits IOB3 to IOB0 in TIOR2, bits CCLR1 and CCLR0 in TCR2, bits TPSC2 to TPSC0 in TCR0 and TCR5, bit NDER15 in NDERH, and bit P17DDR.

TPU Channel 2 Setting	Table Below (1)	Ta	able Below	(2)		
P17DDR	_	0	1	1		
NDER15		_	0	1		
Pin function	TIOCB2 output	P1 ₇	P1 ₇	PO15		
		input	output	output		
		TIOCB2 input *1				
	TCLKD	KD input *2				

Notes: 1. TIOCB2 input when MD3 to MD0 = B'0000, B'01xx, and IOB3 = 1.

2. TCLKD input when the setting for either TCR0 or TCR5 is: TPSC2 to TPSC0 = B'111.

TCLKD input when channels 2 and 4 are set to phase counting mode.

TPU Channel 2 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'0010		B'0011	
IOB3 to IOB0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		B'xx00	Other tha	an B'xx00
CCLR1, CCLR0	_				Other than B'10	B'10
Output function	_	Output compare output	_	_	PWM mode 2 output	_

x: Don't care

P1₆/PO14/TIOCA2 The pin function is switched as shown below according to the combination of the TPU channel 2 setting by bits MD3 to MD0 in TMDR2, bits IOA3 to IOA0 in TIOR2, bits CCLR1 and CCLR0 in TCR2, bit NDER14 in NDERH, and bit P16DDR.

TPU Channel 2 Setting	Table Below (1)	Та	able Below	(2)
P16DDR		0	1	1
NDER14	_	_	0	1
Pin function	TIOCA2 output	P1 ₆ input	P1 ₆ output	PO14 output
		TIOCA2 input *1		

Note: 1. TIOCA2 input when MD3 to MD0 = B'0000, B'01xx, and IOA3 = 1.

TPU Channel 2 Setting	(2)	(1)	(2)	(1)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'001x	B'0011	B'0	011
IOA3 to IOA0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		Other than B'xx00		
CCLR1, CCLR0	_	_	_	_	Other than B'01	B'01
Output function	_	Output compare output	_	PWM mode 1 output *2	PWM mode 2 output	_

x: Don't care

Note: 2. TIOCB2 output is disabled.

P1₅/PO13/TIOCB1/ The pin function is switched as shown below according to the combination of TCLKC the TPU channel 1 setting by bits MD3 to MD0 in TMDR1, bits IOB3 to IOB0 in TIOR1, bits CCLR1 and CCLR0 in TCR1, bits TPSC2 to TPSC0 in TCR0, TCR2, TCR4, and TCR5, bit NDER13 in NDERH, and bit P15DDR.

TPU Channel 1 Setting	Table Below (1)	Та	ıble Below	(2)	
P15DDR	_	0	1	1	
NDER13	_	_	0	1	
Pin function	TIOCB1 output	P1₅ input	P1₅ output	PO13 output	
		TIOCB1 input *1			
	TCLKC	C input *2			

Notes: 1. TIOCB1 input when MD3 to MD0 = B'0000, B'01xx and IOB3 to IOB0 = B'10xx.

 TCLKC input when the setting for either TCR0 or TCR2 is: TPSC2 to TPSC0 = B'110; or when the setting for either TCR4 or TCR5 is TPSC2 to TPSC0 = B'101.

TCLKC input when channels 2 and 4 are set to phase counting mode.

TPU Channel 1 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'0010		B'0011	
IOB3 to IOB0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111	_	B'xx00	Other tha	an B'xx00
CCLR1, CCLR0	_		_	-	Other than B'10	B'10
Output function	_	Output compare output	_	_	PWM mode 2 output	_

x: Don't care

P1₄/PO12/TIOCA1 The pin function is switched as shown below according to the combination of the TPU channel 1 setting by bits MD3 to MD0 in TMDR1, bits IOA3 to IOA0 in TIOR1, bits CCLR1 and CCLR0 in TCR1, bit NDER12 in NDERH, and bit P14DDR.

TPU Channel 1 Setting	Table Below (1)	Та	able Below	(2)
P14DDR		0	1	1
NDER12	_	_	0	1
Pin function	TIOCA1 output	P1₄ input	P1₄ output	PO12 output
		TIC	OCA1 inpu	t *1

Note: 1. TIOCA1 input when MD3 to MD0 = B'0000, B'01xx, IOA3 to IOA0 = B'10xx.

TPU Channel 1 Setting	(2)	(1)	(2)	(1)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'001x	B'0010	B'0	011
IOA3 to IOA0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		Other than B'xx00	Other than B'xx00	
CCLR1, CCLR0	_		_	_	Other than B'01	B'01
Output function	_	Output compare output	_	PWM mode 1 output*2	PWM mode 2 output	_

x: Don't care

Note: 2. TIOCB1 output is disabled.

P1₃/PO11/TIOCD0/ The pin function is switched as shown below according to the combination of TCLKB the TPU channel 0 setting by bits MD3 to MD0 in TMDR0, bits IOD3 to IOD0 in TIOR0L, bits CCLR2 to CCLR0 in TCR0, bits TPSC2 to TPSC0 in TCR0 to TCR2, bit NDER11 in NDERH, and bit P13DDR.

TPU Channel 0 Setting	Table Below (1)	Та	ıble Below	(2)
P13DDR	_	0	1	1
NDER11	_	_	0	1
Pin function	TIOCD0 output	P1 ₃ input	P1 ₃ output	PO11 output
		TIC	OCD0 inpu	t *1
	TCLKB	input *2		

Notes: 1. TIOCD0 input when MD3 to MD0 = B'0000, IOD3 to IOD0 =B'10xx.

TCLKB input when the setting for TCR0 to TCR2 is: TPSC2 to TPSC0 = B'101;

TCLKB input when channels 1 and 5 are set to phase counting mode.

TPU Channel 0 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0		000	B'0010	(-)	B'0011	(-)
IOD3 to IOD0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111	_	B'xx00	Other tha	an B'xx00
CCLR2 to CCLR0	_		_	_	Other than B'110	B'110
Output function	_	Output compare output	_	_	PWM mode 2 output	_

mode.

P1₂/PO10/TIOCC0/ The pin function is switched as shown below according to the combination of TCLKA the TPU channel 0 setting by bits MD3 to MD0 in TMDR0, bits IOC3 to IOC0 in TIOR0L, bits CCLR2 to CCLR0 in TCR0, bits TPSC2 to TPSC0 in TCR0 to TCR5, bit NDER10 in NDERH, and bit P12DDR.

TPU Channel 0 Setting	Table Below (1)	Та	able Below	(2)
P12DDR	_	0	1	1
NDER10	_	_	0	1
Pin function	TIOCC0 output	P1 ₂ input	P1 ₂ output	PO10 output
		TIC	OCC0 inpu	t *1
	TCLKA	input *2		

- Notes: 1. TIOCC0 input when MD3 to MD0 = B'0000, and IOC3 to IOC0 = B'10xx.
 - TCLKA input when the setting for TCR0 to TCR5 is: TPSC2 to TPSC0 = B'100;
 TCLKA input when channels 1 and 5 are set to phase counting

TPU Channel 0 Setting	(2)	(1)	(2)	(1)	(1)	(2)	
MD3 to MD0	B'0	000	B'001x	B'0010	B'0	011	
IOC3 to IOC0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		Oth	her than B'xx00		
CCLR2 to CCLR0	_	_	_	_	Other than B'101	B'101	
Output function	_	Output compare output	_	PWM mode 1 output*3	PWM mode 2 output	_	

x: Don't care

Note: 3. TIOCD0 output is disabled.

When BFA = 1 or BFB = 1 in TMDR0, output is disabled and setting
(2) applies.

DACK1

P1₁/PO9/TIOCB0/ The pin function is switched as shown below according to the combination of the TPU channel 0 setting by bits MD3 to MD0 in TMDR0, bits IOB3 to IOB0 in TIOR0H, bits CCLR2 to CCLR0 in TCR0, bit NDER9 in NDERH, bit SAE1 in DMABCRH, and bit P11DDR.

SAE1	0 1						
TPU Channel 0 Setting	Table Below (1)	Table Below (2)					
P11DDR	_	0 1 1 —					
NDER9	_	_ 0 1 _					
Pin function	TIOCB0 output	P1, P1, PO9 DACK1 input output output					
		TIOCB0 input *1					

Note: 1. TIOCB0 input when MD3 to MD0 = B'0000, and IOB3 to IOB0 = B'10xx.

TPU Channel 0 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0	000	B'0010		B'0011	
IOB3 to IOB0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111	_	B'xx00	Other tha	an B'xx00
CCLR2 to CCLR0	_	_	_	_	Other than B'010	B'010
Output function	_	Output compare output	_	_	PWM mode 2 output	_

P1₀/PO8/TIOCA0/ DACK0

The pin function is switched as shown below according to the combination of the TPU channel 0 setting by bits MD3 to MD0 in TMDR0, bits IOA3 to IOA0 in TIOR0H, bits CCLR2 to CCLR0 in TCR0, bit NDER8 in NDERH, bit SAE0 in DMABCRH, and bit P10DDR.

SAE0		0					
TPU Channel 0 Setting	Table Below (1)	Т	_				
P10DDR	_	0	_				
NDER8	_	_	0	1	_		
Pin function	TIOCA0 output	P1 ₀ input	DACK0 output				
			TIOCAO	input *1			

Note: 1. TIOCA0 input when MD3 to MD0 = B'0000, and IOA3 to IOA0 = B'10xx.

TPU Channel 0 Setting	(2)	(1)	(2)	(1)	(1)	(2)	
MD3 to MD0	B'0	000	B'001x	B'0010	B'0	011	
IOA3 to IOA0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		Oth	er than B'xx00		
CCLR2 to CCLR0	_	_	_	_	Other than B'001	B'001	
Output function	_	Output compare output	_	PWM mode 1 output*2	PWM mode 2 output	_	

Note: 2. TIOCB0 output is disabled.

9.3 Port 2

9.3.1 Overview

Port 2 is an 8-bit I/O port. Port 2 pins also function as PPG output pins (PO7 to PO0), TPU I/O pins (TIOCA3, TIOCB3, TIOCC3, TIOCD3, TIOCA4, TIOCB4, TIOCA5, and TIOCB5) and 8-bit timer I/O pins (TMRI0, TMCI0, TMO0, TMRI1, TMCI1, TMO1). Port 2 pin functions are the same in all operating modes. Port 2 uses Schmitt-triggered input.

Figure 9-2 shows the port 2 pin configuration.

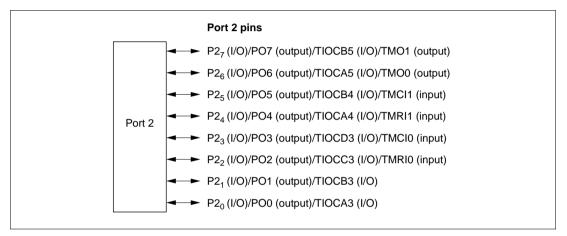


Figure 9-2 Port 2 Pin Functions

9.3.2 Register Configuration

Table 9-4 shows the port 2 register configuration.

Table 9-4 Port 2 Registers

Name	Abbreviation	R/W	Initial Value	Address*
Port 2 data direction register	P2DDR	W	H'00	H'FEB1
Port 2 data register	P2DR	R/W	H'00	H'FF61
Port 2 register	PORT2	R	Undefined	H'FF51

Note: * Lower 16 bits of the address.

Port 2 Data Direction Register (P2DDR)

Bit	:	7	6	5	4	3	2	1	0
		P27DDR	P26DDR	P25DDR	P24DDR	P23DDR	P22DDR	P21DDR	P20DDR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

P2DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 2. P2DDR cannot be read; if it is, an undefined value will be read.

Setting a P2DDR bit to 1 makes the corresponding port 2 pin an output pin, while clearing the bit to 0 makes the pin an input pin.

P2DDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. As the PPG, TPU, and 8-bit timer are initialized by a manual reset*, the pin states are determined by the P2DDR and P2DR specifications.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 2 Data Register (P2DR)

Bit	:	7	6	5	4	3	2	1	0
		P27DR	P26DR	P25DR	P24DR	P23DR	P22DR	P21DR	P20DR
Initial val	ue:	0	0	0	0	0	0	0	0
R/W	:	R/W							

P2DR is an 8-bit readable/writable register that stores output data for the port 2 pins (P2₇ to P2₀).

P2DR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 2 Register (PORT2)

Bit	:	7	6	5	4	3	2	1	0
		P27	P26	P25	P24	P23	P22	P21	P20
Initial va	alue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins P2, to P2,

PORT2 is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port 2 pins ($P2_7$ to $P2_0$) must always be performed on P2DR.

If a port 2 read is performed while P2DDR bits are set to 1, the P2DR values are read. If a port 2 read is performed while P2DDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORT2 contents are determined by the pin states, as P2DDR and P2DR are initialized. PORT2 retains its prior state after a manual reset*, and in software standby mode.

9.3.3 Pin Functions

Port 2 pins also function as PPG output pins (PO7 to PO0) and TPU I/O pins (TIOCA3, TIOCB3, TIOCC3, TIOCD3, TIOCA4, TIOCB4, TIOCA5, and TIOCB5), and 8-bit timer I/O pins (TMRI0, TMCI0, TMO0, TMRI1, TMCI1, and TMO1). Port 2 pin functions are shown in table 9-5.

Table 9-5 Port 2 Pin Functions

Pin Selection Method and Pin Functions

P2₇/PO7/TIOCB5/

The pin function is switched as shown below according to the combination of the TPU channel 5 setting by bits MD3 to MD0 in TMDR5, bits IOB3 to IOB0 in TIOR5, bits CCLR1 and CCLR0 in TCR5, bit NDER7 in NDERL, bits OS3 to OS0 in TCSR1, and bit P27DDR.

OS3 to OS0		All 0				
TPU Channel 5 Setting	Table Below (1)	Т	_			
P27DDR	_	0	_			
NDER7	_	_	0	1	_	
Pin function	TIOCB5 output	P2 ₇ input	P2 ₇ output	PO7 output	TMO1 output	
		TIOCB5 input *				

Note: * TIOCB5 input when MD3 to MD0 = B'0000, B'01xx, and IOB3 = 1.

TPU Channel 5 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'0010		B'0011	
IOB3 to IOB0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		B'xx00	Other tha	an B'xx00
CCLR1, CCLR0	_				Other than B'10	B'10
Output function	_	Output compare output	_	_	PWM mode 2 output	_

P2₆/PO6/TIOCA5/ TMO0 The pin function is switched as shown below according to the combination of the TPU channel 5 setting by bits MD3 to MD0 in TMDR5, bits IOA3 to IOA0 in TIOR5, bits CCLR1 and CCLR0 in TCR5, bit NDER6 in NDERL, bits OS3 to OS0 in TCSR0, and bit P26DDR.

OS3 to OS0		Al		Any 1	
TPU Channel 5 Setting	Table Below (1)	Table Below (2)			_
P26DDR	_	0	_		
NDER6	_	_	0	1	_
Pin function	TIOCA5 output	P2 ₆ input	P2 ₆ output	PO6 output	TMO0 output
			TIOCA5	input *1	

Note: 1. TIOCA5 input when MD3 to MD0 = B'0000, B'01xx, and IOA3 = 1.

TPU Channel 5 Setting	(2)	(1)	(2)	(1)	(1)	(2)	
MD3 to MD0	B'0000	, B'01xx	B'001x	B'0010	B'0	011	
IOA3 to IOA0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		Oth	Other than B'xx00		
CCLR1, CCLR0	_	_		_	Other than B'01	B'01	
Output function	_	Output compare output	-	PWM mode 1 output*2	PWM mode 2 output		

x: Don't care

Note: 2. TIOCB5 output is disabled.

P2₅/PO5/TIOCB4/ TMCI1 This pin is used as the 8-bit timer external clock input pin when external clock is selected with bits CKS2 to CKS0 in TCR1.

The pin function is switched as shown below according to the combination of the TPU channel 4 setting by bits MD3 to MD0 in TMDR4 and bits IOB3 to IOB0 in TIOR4, bits CCLR1 and CCLR0 in TCR4, bit NDER5 in NDERL, and bit P25DDR.

TPU Channel 4 Setting	Table Below (1)	Table Below (2)				
P25DDR	_	0	1	1		
NDER5	_	_	0	1		
Pin function	TIOCB4 output	P2₅ input	P2₅ output	PO5 output		
		TIOCB4 input *1				
	TMCI	1 input				

Note: 1. TIOCB4 input when MD3 to MD0 = B'0000, B'01xx, and IOB3 to IOB0 = B'10xx.

TPU Channel 4 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'0010		B'0011	
IOB3 to IOB0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		B'xx00	Other tha	an B'xx00
CCLR1, CCLR0	_	_		_	Other than B'10	B'10
Output function	_	Output compare output		_	PWM mode 2 output	

P2₄/PO4/TIOCA4/ TMRI1

This pin is used as the 8-bit timer counter reset pin when bits CCLR1 and CCLR0 in TCR1 are both set to 1.

The pin function is switched as shown below according to the combination of the TPU channel 4 setting by bits MD3 to MD0 in TMDR4, bits IOA3 to IOA0 in TIOR4, bits CCLR1 and CCLR0 in TCR4, bit NDER4 in NDERL, and bit P24DDR.

TPU Channel 4 Setting	Table Below (1)	Table Below (2)			
P24DDR	_	0	1	1	
NDER4	_	_	0	1	
Pin function	TIOCA4 output	P2₄ input	P2 ₄ output	PO4 output	
		TIOCA4 input *1			
	TMRI	1 input			

Note: 1. TIOCA4 input when MD3 to MD0 = B'0000, B'01xx, and IOA3 to IOA0 = B'10xx.

TPU Channel 4 Setting	(2)	(1)	(2)	(1)	(1)	(2)
MD3 to MD0	B'0000	, B'01xx	B'001x	B'0010	B'0	011
IOA3 to IOA0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		Oth	er than B'x	xx00
CCLR1, CCLR0	_	_		_	Other than B'01	B'01
Output function	_	Output compare output	_	PWM mode 1 output*2	PWM mode 2 output	_

Note: 2. TIOCB4 output is disabled.

P2₃/PO3/TIOCD3/ TMCI0

This pin is used as the 8-bit timer external clock input pin when external clock is selected with bits CKS2 to CKS0 in TCR0.

The pin function is switched as shown below according to the combination of the TPU channel 3 setting by bits MD3 to MD0 in TMDR3, bits IOD3 to IOD0 in TIOR3L, bits CCLR2 to CCLR0 in TCR3, bit NDER3 in NDERL, and bit P23DDR.

TPU Channel 3 Setting	Table Below (1)	Table Below (2)			
P23DDR	_	0	1	1	
NDER3	_	_	0	1	
Pin function	TIOCD3 output	P2 ₃ input	P2 ₃ output	PO3 output	
		TIOCD3 input *1			
	TMCI	I0 input			

Note: 1. TIOCD3 input when MD3 to MD0 = B'0000, and IOD3 to IOD0 = B'10xx.

TPU Channel 3 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0	000	B'0010		B'0011	
IOD3 to IOD0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		B'xx00	Other tha	an B'xx00
CCLR2 to CCLR0	_	_	_	_	Other than B'110	B'110
Output function	_	Output compare output	_	_	PWM mode 2 output	_

P2₂/PO2/TIOCC3/ TMRI0

This pin is used as the 8-bit timer counter reset pin when bits CCLR1 and CCLR0 in TCR0 are both set to 1.

The pin function is switched as shown below according to the combination of the TPU channel 3 setting by bits MD3 to MD0 in TMDR3, bits IOC3 to IOC0 in TIOR3L, bits CCLR2 to CCLR0 in TCR3, bit NDER2 in NDERL, and bit P22DDR.

TPU Channel 3 Setting	Table Below (1)	Table Below (2)				
P22DDR	_	0	1	1		
NDER2	_	_	0	1		
Pin function	TIOCC3 output	P2 ₂ input	P2 ₂ output	PO2 output		
		TIOCC3 input *1				
	TMRI	RI0 input				

Note: 1. TIOCC3 input when MD3 to MD0 = B'0000, and IOC3 to IOC0 = B'10xx.

TPU Channel 3 Setting	(2)	(1)	(2)	(1)	(1)	(2)		
MD3 to MD0	B'0	000	B'001x	B'0010	B'0	B'0011		
IOC3 to IOC0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111	B'xx00	Oth	Other than B'xx00			
CCLR2 to CCLR0	_	_	_	_	Other than B'101	B'101		
Output function	_	Output compare output	_	PWM mode 1 output*2	PWM mode 2 output	_		

x: Don't care

Note: 2. TIOCD3 output is disabled.

When BFA = 1 or BFB = 1 in TMDR3, output is disabled and setting (2) applies.

P2₁/PO1/TIOCB3

The pin function is switched as shown below according to the combination of the TPU channel 3 setting by bits MD3 to MD0 in TMDR3, bits IOB3 to IOB0 in TIOR3H, bits CCLR2 to CCLR0 in TCR3, bit NDER1 in NDERL, and bit P21DDR.

TPU Channel 3 Setting	Table Below (1)	Table Below (2)			
P21DDR	_	0	1	1	
NDER1	_	_	0	1	
Pin function	TIOCB3 output	P2₁ input	P2₁ output	PO1 output	
		TIOCB3 input *1			

Note: 1. TIOCB3 input when MD3 to MD0 = B'0000, and IOB3 to IOB0 = B'10xx.

TPU Channel 3 Setting	(2)	(1)	(2)	(2)	(1)	(2)
MD3 to MD0	B'0	B'0000			B'0011	
IOB3 to IOB0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111		B'xx00 Other than B'xx00		
CCLR2 to CCLR0	_	_	-	_	Other than B'010	B'010
Output function	_	Output compare output	_	_	PWM mode 2 output	_

P2₀/PO0/TIOCA3

The pin function is switched as shown below according to the combination of the TPU channel 3 setting by bits MD3 to MD0 in TMDR3, bits IOA3 to IOA0 in TIOR3H, bits CCLR2 to CCLR0 in TCR3, bit NDER0 in NDERL, and bit P20DDR.

TPU Channel 3 Setting	Table Below (1)	Table Below (2)				
P20DDR		0	1	1		
NDER0	_	_	0	1		
Pin function	TIOCA3 output	P2 ₀ P2 ₀ PO0 input output output				
		TIOCA3 input *1				

Note: 1. TIOCA3 input when MD3 to MD0 = B'0000, and IOA3 to IOA0 = B'10xx.

TPU Channel 3 Setting	(2)	(1)	(2)	(1)	(1)	(2)		
MD3 to MD0	B'0	000	B'001x	B'0010	B'0	B'0011		
IOA3 to IOA0	B'0000 B'0100 B'1xxx	B'0001 to B'0011 B'0101 to B'0111	B'xx00	Other than B'xx00				
CCLR2 to CCLR0	_	_	_	_	Other than B'001	B'001		
Output function	_	Output compare output	_	PWM mode 1 output*2	PWM mode 2 output	_		

x: Don't care

Note: 2. TIOCB3 output is disabled.

9.4 Port 3

9.4.1 Overview

Port 3 is a 6-bit I/O port. Port 3 pins also function as SCI I/O pins (TxD0, RxD0, SCK0, TxD1, RxD1, and SCK1). Port 3 pin functions are the same in all operating modes.

Figure 9-3 shows the port 3 pin configuration.

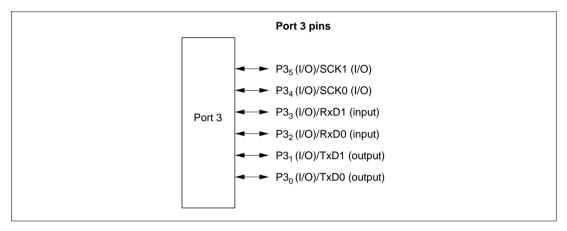


Figure 9-3 Port 3 Pin Functions

9.4.2 Register Configuration

Table 9-6 shows the port 3 register configuration.

 Table 9-6
 Port 3 Registers

Name	Abbreviation	R/W	Initial Value*2	Address*1
Port 3 data direction register	P3DDR	W	H'00	H'FEB2
Port 3 data register	P3DR	R/W	H'00	H'FF62
Port 3 register	PORT3	R	Undefined	H'FF52
Port 3 open drain control register	P3ODR	R/W	H'00	H'FF76

Notes: 1. Lower 16 bits of the address.

2. Value of bits 5 to 0.

Port 3 Data Direction Register (P3DDR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	P35DDR	P34DDR	P33DDR	P32DDR	P31DDR	P30DDR
Initial valu	e :	Undefined	Undefined	0	0	0	0	0	0
R/W	:	_	_	W	W	W	W	W	W

P3DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 3. Bits 7 and 6 are reserved. P3DDR cannot be read; if it is, an undefined value will be read

Setting a P3DDR bit to 1 makes the corresponding port 3 pin an output pin, while clearing the bit to 0 makes the pin an input pin.

P3DDR is initialized to H'00 (bits 5 to 0) by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. As the SCI is initialized, the pin states are determined by the P3DDR and P3DR specifications.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 3 Data Register (P3DR)

Bit	7	6	5	4	3	2	1	0
	_	_	P35DR	P34DR	P33DR	P32DR	P31DR	P30DR
Initial value	Undefined	Undefined	0	0	0	0	0	0
R/W	_		R/W	R/W	R/W	R/W	R/W	R/W

P3DR is an 8-bit readable/writable register that stores output data for the port 3 pins (P3₅ to P3₀).

Bits 7 and 6 are reserved; they return an undetermined value if read, and cannot be modified.

P3DR is initialized to H'00 (bits 5 to 0) by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Port 3 Register (PORT3)

Bit	:	7	6	5	4	3	2	1	0
		_	_	P35	P34	P33	P32	P31	P30
Initial va	lue :	Undefined	Undefined	*	*	*	*	*	*
R/W	:	_	_	R	R	R	R	R	R

Note: * Determined by state of pins P3₅ to P3₀.

PORT3 is an 8-bit read-only register that shows the pin states. Writing of output data for the port 3 pins (P3₅ to P3₀) must always be performed on P3DR.

Bits 7 and 6 are reserved; they return an undetermined value if read, and cannot be modified.

If a port 3 read is performed while P3DDR bits are set to 1, the P3DR values are read. If a port 3 read is performed while P3DDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORT3 contents are determined by the pin states, as P3DDR and P3DR are initialized. PORT3 retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 3 Open Drain Control Register (P3ODR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	P35ODR	P34ODR	P33ODR	P32ODR	P31ODR	P30ODR
Initial value):	Undefined	Undefined	0	0	0	0	0	0
R/W	:	_	_	R/W	R/W	R/W	R/W	R/W	R/W

P3ODR is an 8-bit readable/writable register that controls the PMOS on/off status for each port 3 pin (P3₅ to P3₀).

Bits 7 and 6 are reserved; they return an undetermined value if read, and cannot be modified.

Setting a P3ODR bit to 1 makes the corresponding port 3 pin an NMOS open-drain output pin, while clearing the bit to 0 makes the pin a CMOS output pin.

P3ODR is initialized to H'00 (bits 5 to 0) by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

9.4.3 Pin Functions

Port 3 pins also function as SCI I/O pins (TxD0, RxD0, SCK0, TxD1, RxD1, and SCK1). Port 3 pin functions are shown in table 9-7.

Table 9-7 Port 3 Pin Functions

Pin Selection Method and Pin Functions

P3₅/SCK1 The pin function is switched as shown below according to the combination of bit C/A in the SCI1 SMR, bits CKE0 and CKE1 in SCR, and bit P35DDR.

CKE1		1			
C/A		0	1	_	
CKE0	(0	1	_	_
P35DDR	0 1		_	_	_
Pin function	P3₅ input pin	P3 ₅ output pin*	SCK1 output pin*	SCK1 output pin*	SCK1 input pin

Note: * When P35ODR = 1, the pin becomes an NMOS open-drain output.

P3₄/SCK0

The pin function is switched as shown below according to the combination of bit C/\overline{A} in the SCI0 SMR, bits CKE0 and CKE1 in SCR, and bit P34DDR.

				•	
CKE1		1			
C/A		0		1	_
CKE0	(0	1	_	_
P34DDR	0	1	_	_	
Pin function	P3₄ input pin	P3 ₄ output pin*	SCK0 output pin*	SCK0 output pin*	SCK0 input pin

Note: * When P34ODR = 1, the pin becomes an NMOS open-drain output.

Pin	Selection Meth	od and Pin Function	าร			
P3₃/RxD1		is switched as show I1 SCR, and bit P33D		the combination of		
	RE		0	1		
	P33DDR	0	1	_		
	Pin function	P3 ₃ input pin	P3 ₃ output pin*	RxD1 input pin		
	Note: * When	P33ODR = 1, the pin	becomes an NMOS	open-drain output.		
P3 ₂ /RxD0		is switched as show 10 SCR, and bit P32D		the combination of		
	RE		0	1		
	P32DDR	0	1	_		
	Pin function	P3 ₂ input pin	P3 ₂ output pin*	RxD0 input pin		
P3 ₁ /TxD1	The pin function	P32ODR = 1, the pin is switched as show I1 SCR, and bit P31D	n below according to			
	TE	I	0	1		
	P31DDR	0	1	_		
	Pin function	P3₁ input pin	P3₁ output pin*	TxD1 output pin*		
	Note: * When P31ODR = 1, the pin becomes an NMOS open-drain output.					
P3 ₀ /TxD0		is switched as show I0 SCR, and bit P30D		the combination of		
	TE	0		1		
	P30DDR	0	1	_		
	Pin function	P3 ₀ input pin	P3 ₀ output pin*	TxD0 output pin*		
		-0 1 - 1	-0 1 1			

9.5 Port 4

9.5.1 Overview

Port 4 is an 8-bit input-only port. Port 4 pins also function as A/D converter analog input pins (AN0 to AN7) and D/A converter analog output pins (DA0 and DA1). Port 4 pin functions are the same in all operating modes. Figure 9-4 shows the port 4 pin configuration.

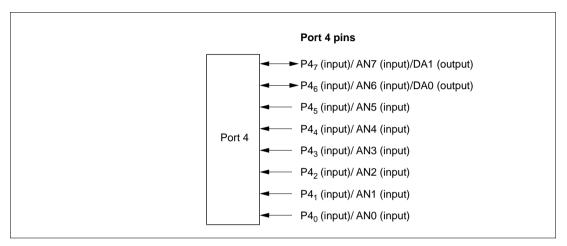


Figure 9-4 Port 4 Pin Functions

9.5.2 Register Configuration

Table 9-8 shows the port 4 register configuration. Port 4 is an input-only port, and does not have a data direction register or data register.

Table 9-8 Port 4 Registers

Name	Abbreviation	R/W	Initial Value	Address*
Port 4 register	PORT4	R	Undefined	H'FF53

Note: * Lower 16 bits of the address.

Port 4 Register (PORT4): The pin states are always read when a port 4 read is performed.

Bit	:	7	6	5	4	3	2	1	0
		P47	P46	P45	P44	P43	P42	P41	P40
Initial valu	ıe:	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins P4, to P40.

9.5.3 Pin Functions

Port 4 pins also function as A/D converter analog input pins (AN0 to AN7) and D/A converter analog output pins (DA0 and DA1).

9.6 Port 5

9.6.1 Overview

Port 5 is a 4-bit I/O port. Port 5 pins also function as SCI I/O pins (TxD2, RxD2, and SCK2) and the A/D converter input pin (ADTRG). Port 5 pin functions are the same in all operating modes. Figure 9-5 shows the port 5 pin configuration.

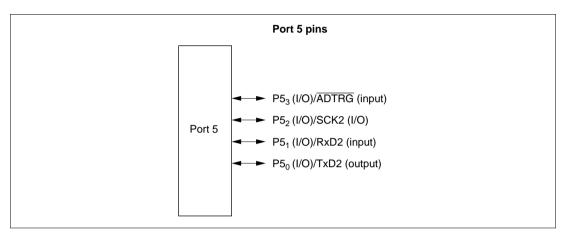


Figure 9-5 Port 5 Pin Functions

9.6.2 Register Configuration

Table 9-9 shows the port 5 register configuration.

Table 9-9 Port 5 Registers

Name	Abbreviation	R/W	Initial Value*2	Address*1
Port 5 data direction register	P5DDR	W	H'0	H'FEB4
Port 5 data register	P5DR	R/W	H'0	H'FF64
Port 5 register	PORT5	R	Undefined	H'FF54

Notes: 1. Lower 16 bits of the address.

2. Value of bits 3 to 0.

Port 5 Data Direction Register (P5DDR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	P53DDR	P52DDR	P51DDR	P50DDR
Initial va	alue :	Undefined	Undefined	Undefined	Undefined	0	0	0	0
R/W	:	_	_	_	_	W	W	W	W

P5DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 5. Bits 7 to 4 are reserved. P5DDR cannot be read; if it is, an undefined value will be read.

Setting a P5DDR bit to 1 makes the corresponding port 5 pin an output pin, while clearing the bit to 0 makes the pin an input pin.

P5DDR is initialized to H'0 (bits 3 to 0) by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. As the SCI is initialized, the pin states are determined by the P5DDR and P5DR specifications.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 5 Data Register (P5DR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	P53DR	P52DR	P51DR	P50DR
Initial v	alue :	Undefined	Undefined	Undefined	Undefined	0	0	0	0
R/W	:	_	_	_	_	R/W	R/W	R/W	R/W

P5DR is an 8-bit readable/writable register that stores output data for the port 5 pins (P5₃ to P5₀).

Bits 7 to 4 are reserved; they return an undetermined value if read, and cannot be modified.

P5DR is initialized to H'0 (bits 3 to 0) by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Port 5 Register (PORT5)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	P53	P52	P51	P50
Initial valu	ıe:	Undefined	Undefined	Undefined	Undefined	*	*	*	*
R/W	:		_	_	_	R	R	R	R

Note: * Determined by state of pins P5₃ to P5₀.

PORT5 is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port 5 pins ($P5_3$ to $P5_0$) must always be performed on P5DR.

Bits 7 to 4 are reserved; they return an undetermined value if read, and cannot be modified.

If a port 5 read is performed while P5DDR bits are set to 1, the P5DR values are read. If a port 5 read is performed while P5DDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORT5 contents are determined by the pin states, as P5DDR and P5DR are initialized. PORT5 retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

9.6.3 Pin Functions

Port 5 pins also function as SCI I/O pins (TxD2, RxD2, and SCK2), and the A/D converter input pin (ADTRG). Port 5 pin functions are shown in table 9-10.

Table 9-10 Port 5 Pin Functions

Pin Selection Method and Pin Functions

P5₃/ADTRG

The pin function is switched as shown below according to the combination of bits TRGS1 and TRGS0 in the A/D converter ADCR, and bit P53DDR.

P53DDR	0	1
Pin function	P5 ₃ input pin	P5 ₃ output pin
	ADTRG i	nput pin*

Note: * \overline{ADTRG} input when TRGS0 = TRGS1 = 1.

P5₂/SCK2

The pin function is switched as shown below according to the combination of bit C/Ā in the SCI2 SMR, bits CKE0 and CKE1 in SCR, and bit P52DDR.

CKE1		1			
C/Ā	0			1	_
CKE0	()	1		
P52DDR	0	1	_	_	_
Pin function	P5 ₂ input pin	P5 ₂ output pin	SCK2 output pin	SCK2 output pin	SCK2 input pin

P5₁/RxD2

The pin function is switched as shown below according to the combination of bit RE in the SCI2 SCR, and bit P51DDR.

RE	1	1	
P51DDR	0	_	
Pin function	P5₁ input pin	P5₁ output pin	RxD2 input pin

P5₀/TxD2

The pin function is switched as shown below according to the combination of bit TE in the SCI2 SCR, and bit P50DDR.

TE		1	
P50DDR	0	_	
Pin function	P5 ₀ input pin	P5 ₀ output pin	TxD2 output pin

9.7 Port 6

9.7.1 Overview

Port 6 is an 8-bit I/O port. Port 6 pins also function as interrupt input pins ($\overline{IRQ0}$ to $\overline{IRQ3}$), DMAC I/O pins ($\overline{DREQ0}$, $\overline{TEND0}$, $\overline{DREQ1}$, and $\overline{TEND1}$), and bus control output pins ($\overline{CS4}$ to $\overline{CS7}$). The functions of pins P6₅ to P6₂ are the same in all operating modes, while the functions of pins P6₇, P6₆, P6₁, and P6₀ change according to the operating mode. Pins P6₇ to P6₄ are schmitt-triggered inputs. Figure 9-6 shows the port 6 pin configuration.

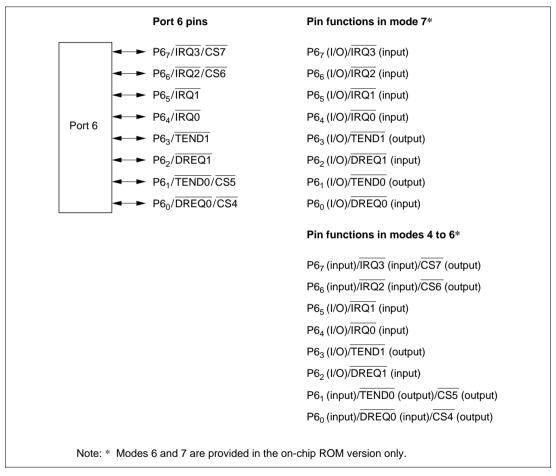


Figure 9-6 Port 6 Pin Functions

9.7.2 Register Configuration

Table 9-11 shows the port 6 register configuration.

Table 9-11 Port 6 Registers

Name	Abbreviation	R/W	Initial Value	Address*
Port 6 data direction register	P6DDR	W	H'00	H'FEB5
Port 6 data register	P6DR	R/W	H'00	H'FF65
Port 6 register	PORT6	R	Undefined	H'FF55

Note: * Lower 16 bits of the address.

Port 6 Data Direction Register (P6DDR)

Bit	:	7	6	5	4	3	2	1	0
		P67DDR	P66DDR	P65DDR	P64DDR	P63DDR	P62DDR	P61DDR	P60DDR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

P6DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 6. P6DDR cannot be read; if it is, an undefined value will be read.

Setting a P6DDR bit to 1 makes the corresponding port 6 pin an output pin, while clearing the bit to 0 makes the pin an input pin.

P6DDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. As the DMAC is initialized by a manual reset*, the pin states are determined by the P6DDR and P6DR specifications.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 6 Data Register (P6DR)

Bit	:	7	6	5	4	3	2	1	0
		P67DR	P66DR	P65DR	P64DR	P63DR	P62DR	P61DR	P60DR
Initial val	ue:	0	0	0	0	0	0	0	0
R/W	:	R/W							

P6DR is an 8-bit readable/writable register that stores output data for the port 6 pins (P6₇ to P6₀).

P6DR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port 6 Register (PORT6)

Bit	:	7	6	5	4	3	2	1	0
		P67	P66	P65	P64	P63	P62	P61	P60
Initial va	lue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins P6, to P6,.

PORT6 is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port 6 pins ($P6_7$ to $P6_0$) must always be performed on P6DR.

If a port 6 read is performed while P6DDR bits are set to 1, the P6DR values are read. If a port 6 read is performed while P6DDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORT6 contents are determined by the pin states, as P6DDR and P6DR are initialized. PORT6 retains its prior state after a manual reset*, and in software standby mode.

9.7.3 Pin Functions

Port 6 pins also function as interrupt input pins ($\overline{IRQ0}$ to $\overline{IRQ3}$), DMAC I/O pins ($\overline{DREQ0}$, $\overline{TEND0}$, $\overline{DREQ1}$, and $\overline{TEND1}$), and bus control output pins ($\overline{CS4}$ to $\overline{CS7}$). Port 6 pin functions are shown in table 9-12.

Table 9-12 Port 6 Pin Functions

Pin	Selection Meth	nod and Pin Fur	nctions						
P6 ₇ /ĪRQ3/CS7	The pin function	n is switched as	shown below ac	cording to bit Po	67DDR.				
	Mode	Mod	le 7*	Modes 4 to 6*					
	P67DDR	0	1	0	1				
	Pin function	P6 ₇ input pin	P6 ₇ output pin	P6 ₇ input pin	CS7 output pir				
			ıpt input pin						
P6 ₆ /IRQ2/CS6	The pin function	The pin function is switched as shown below according to bit P66D							
	Mode	Mod	le 7*	Modes	4 to 6*				
	P66DDR	0	1	0	1				
	Pin function	P6 ₆ input pin	P6 ₆ output pin	P6 ₆ input pin	CS6 output pir				
			ĪRQ2 interru	ıpt input pin					
P6 ₅ /IRQ1	The pin function	n is switched as	shown below ac	cording to bit Po	65DDR.				
	P65DDR		0	1					
	Pin function	P6₅ in	put pin	P6 ₅ output pin					
			IRQ1 interru	ıpt input pin					
P6₄/IRQ0	The pin function	n is switched as	shown below ac	cording to bit Po	64DDR.				
	P64DDR		0		1				
	Pin function	P6₄ in	put pin	P6₄ ou	tput pin				
			IRQ0 interru	upt input pin					

Pin

Selection Method and Pin Functions

P6₃/TEND1

The pin function is switched as shown below according to the combination of bit TEE1 in the DMAC DMATCR, and bit P63DDR.

TEE1	1	0				
P63DDR	0	1	_			
Pin function	P6 ₃ input pin	P6 ₃ output pin	TEND1 output			

P6₂/DREQ1

The pin function is switched as shown below according to bit P62DDR.

		· · · · · · · · · · · · · · · · · · ·					
P62DDR	0	1					
Pin function	P6 ₂ input pin	P6 ₂ output pin					
	DERQ1 input						

P6₁/TEND0/CS5

The pin function is switched as shown below according to the combination of bit TEE0 in the DMAC DMATCR, and bit P61DDR.

Mode		Mode 7*		Modes 4 to 6*			
TEE0	()	1	(1		
P61DDR	0	1	_	0 1		_	
Pin function	P6₁ input pin	P6₁ output pin	TEND0 output	P6₁ CS5 input pin output pin		TEND0 output	

P6₀/DREQ0/CS4 The pin function is switched as shown below according to bit P60DDR.

•									
Mode	Mod	le 7*	Modes 4 to 6*						
P60DDR	0	1	0	1					
Pin function	P6 ₀ input pin	P6 ₀ output pin	P6 ₀ input pin	CS4 output pin					
	DREQ0 input								

Note: * Modes 6 and 7 are provided in the on-chip ROM version only.

9.8 Port A

9.8.1 Overview

Port A is an 8-bit I/O port. Port A pins also function as address bus outputs and interrupt input pins ($\overline{IRQ4}$ to $\overline{IRQ7}$). The pin functions change according to the operating mode.

Port A has a built-in MOS input pull-up function that can be controlled by software. Pins PA_7 to PA_4 are schmitt-triggered inputs.

Figure 9-7 shows the port A pin configuration.

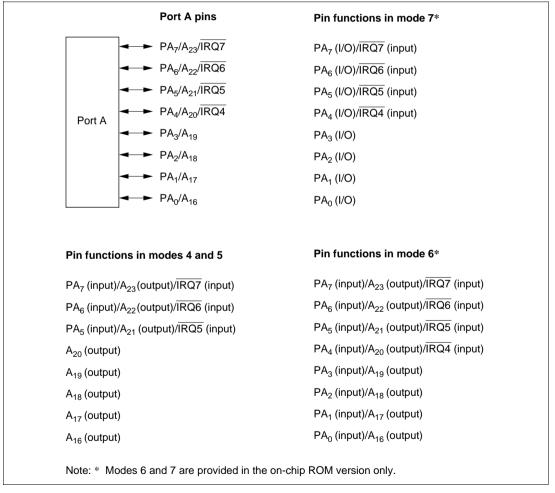


Figure 9-7 Port A Pin Functions

9.8.2 Register Configuration

Table 9-13 shows the port A register configuration.

Table 9-13 Port A Registers

Name	Abbreviation	R/W	Initial Value	Address*
Port A data direction register	PADDR	W	H'00	H'FEB9
Port A data register	PADR	R/W	H'00	H'FF69
Port A register	PORTA	R	Undefined	H'FF59
Port A MOS pull-up control register*	² PAPCR	R/W	H'00	H'FF70
Port A open-drain control register*2	PAODR	R/W	H'00	H'FF77

Notes: 1 Lower 16 bits of the address

2. PAPCR and PAODR settings are prohibited in the ROMless version.

Port A Data Direction Register (PADDR)

Bit	:	7	6	5	4	3	2	1	0
		PA7DDR	PA6DDR	PA5DDR	PA4DDR	PA3DDR	PA2DDR	PA1DDR	PA0DDR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

PADDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port A. PADDR cannot be read; if it is, an undefined value will be read.

PADDR is initialized to H'00 by a power-on reset and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. The OPE bit in SBYCR is used to select whether the address output pins retain their output state or become high-impedance when a transition is made to software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Mode 7

Setting a PADDR bit to 1 makes the corresponding port A pin an output port, while clearing the bit to 0 makes the pin an input port.

Modes 4 and 5

The corresponding port A pins are address outputs irrespective of the value of bits PA4DDR to PA0DDR.

Setting one of bits PA7DDR to PA5DDR to 1 makes the corresponding port A pin an address output, while clearing the bit to 0 makes the pin an input port.

• Mode 6

Setting a PADDR bit to 1 makes the corresponding port A pin an address output while clearing the bit to 0 makes the pin an input port.

Port A Data Register (PADR)

Bit	:	7	6	5	4	3	2	1	0
		PA7DR	PA6DR	PA5DR	PA4DR	PA3DR	PA2DR	PA1DR	PA0DR
Initial value	:	0	0	0	0	0	0	0	0
R/W	:	R/W							

PADR is an 8-bit readable/writable register that stores output data for the port A pins (PA_7 to PA_0).

PADR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port A Register (PORTA)

Bit	:	7	6	5	4	3	2	1	0
		PA7	PA6	PA5	PA4	PA3	PA2	PA1	PA0
Initial value:		*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins PA₇ to PA₀.

PORTA is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port A pins $(PA_7 \text{ to } PA_0)$ must always be performed on PADR.

If a port A read is performed while PADDR bits are set to 1, the PADR values are read. If a port A read is performed while PADDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTA contents are determined by the pin states, as PADDR and PADR are initialized. PORTA retains its prior state after a manual reset*, and in software standby mode.

Port A MOS Pull-Up Control Register (PAPCR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PA7PCR	PA6PCR	PA5PCR	PA4PCR	PA3PCR	PA2PCR	PA1PCR	PA0PCR
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PAPCR is an 8-bit readable/writable register that controls the MOS input pull-up function incorporated into port A on an individual bit basis.

All the bits are valid in modes 6 and 7, and bits 7 to 5 are valid in modes 4 and 5. When a PADDR bit is cleared to 0 (input port setting), setting the corresponding PAPCR bit to 1 turns on the MOS input pull-up for the corresponding pin.

PAPCR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port A Open Drain Control Register (PAODR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PA7ODR	PA6ODR	PA5ODR	PA4ODR	PA3ODR	PA2ODR	PA10DR	PA0ODR
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PAODR is an 8-bit readable/writable register that controls whether PMOS is on or off for each port A pin $(PA_7 \text{ to } PA_0)$.

All bits are valid in mode 7.

Setting a PAODR bit to 1 makes the corresponding port A pin an NMOS open-drain output, while clearing the bit to 0 makes the pin a CMOS output.

PAODR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

9.8.3 Pin Functions

Mode 7 (on-chip ROM version only): In mode 7, port A pins function as I/O ports and interrupt input pins. Input or output can be specified for each pin on an individual bit basis. Setting a PADDR bit to 1 makes the corresponding port A pin an output port, while clearing the bit to 0 makes the pin an input port.

Port A pin functions in mode 7 are shown in figure 9-8.

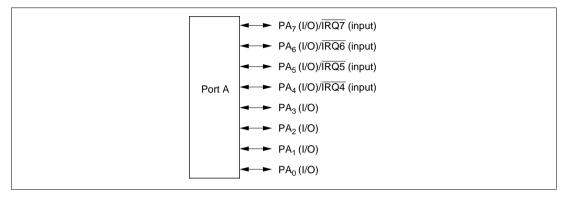


Figure 9-8 Port A Pin Functions (Mode 7)

Modes 4 and 5: In modes 4 and 5, the lower 5 bits of port A are designated as address outputs automatically, while the upper 3 bits function as address outputs or input ports and interrupt input pins. Input or output can be specified individually for the upper 3 bits. Setting one of bits PA7DDR to PA5DDR to 1 makes the corresponding port A pin an address output, while clearing the bit to 0 makes the pin an input port.

Port A pin functions in modes 4 and 5 are shown in figure 9-9.

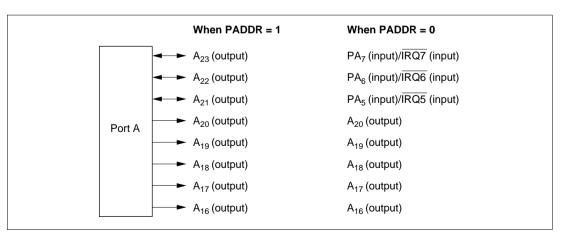


Figure 9-9 Port A Pin Functions (Modes 4 and 5)

Mode 6 (on-chip ROM version only): In mode 6, port A pins function as address outputs or input ports and interrupt input pins. Input or output can be specified on an individual bit basis. Setting a PADDR bit to 1 makes the corresponding port A pin an address output, while clearing the bit to 0 makes the pin an input port.

Port A pin functions in mode 6 are shown in figure 9-10.

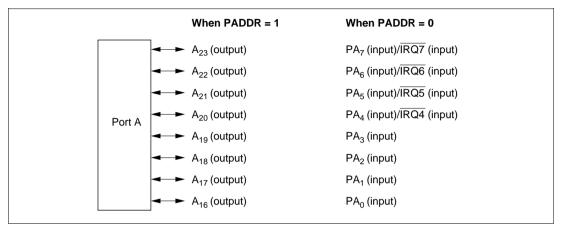


Figure 9-10 Port A Pin Functions (Mode 6)

9.8.4 MOS Input Pull-Up Function (On-Chip ROM Version Only)

Port A has a built-in MOS input pull-up function that can be controlled by software. This MOS input pull-up function can be used by pins PA_7 to PA_5 in modes 4 and 5, and by all pins in modes 6 and 7. MOS input pull-up can be specified as on or off on an individual bit basis.

When a PADDR bit is cleared to 0, setting the corresponding PAPCR bit to 1 turns on the MOS input pull-up for that pin.

The MOS input pull-up function is in the off state after a power-on reset, and in hardware standby mode. The prior state is retained after a manual reset*, and in software standby mode.

Table 9-14 summarizes the MOS input pull-up states.

Table 9-14 MOS Input Pull-Up States (Port A)

Modes		Power-On Reset	Hardware Standby Mode		Software Standby Mode	In Other Operations
6, 7	PA ₇ to PA ₀	OFF		ON/OFF		
4, 5	PA ₇ to PA ₅	_		ON/OFF		
	PA ₄ to PA ₀	_		OFF		

Legend:

OFF: MOS input pull-up is always off.

ON/OFF: On when PADDR = 0 and PAPCR = 1; otherwise off.

9.9 Port B

9.9.1 Overview

Port B is an 8-bit I/O port. Port B has an address bus output function, and the pin functions change according to the operating mode.

Port B has a built-in MOS input pull-up function that can be controlled by software. (on-chip ROM version only)

Figure 9-11 shows the port B pin configuration.

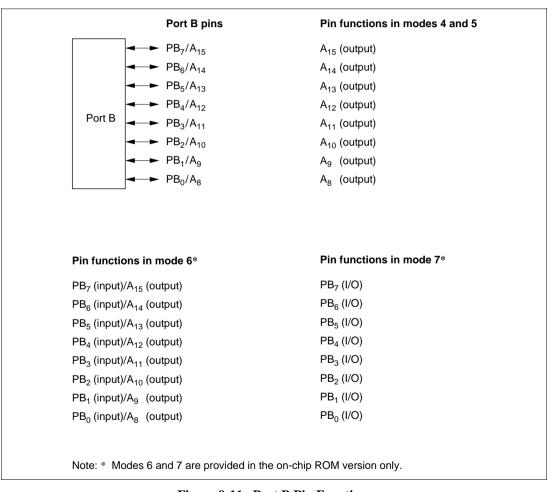


Figure 9-11 Port B Pin Functions

9.9.2 Register Configuration (On-Chip ROM Version Only)

Table 9-15 shows the port B register configuration.

Table 9-15 Port B Registers

Name	Abbreviation	R/W	Initial Value	Address *
Port B data direction register	PBDDR	W	H'00	H'FEBA
Port B data register	PBDR	R/W	H'00	H'FF6A
Port B register	PORTB	R	Undefined	H'FF5A
Port B MOS pull-up control register	PBPCR	R/W	H'00	H'FF71

Note: * Lower 16 bits of the address.

Port B Data Direction Register (PBDDR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PB7DDR	PB6DDR	PB5DDR	PB4DDR	PB3DDR	PB2DDR	PB1DDR	PB0DDR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

PBDDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port B. PBDDR cannot be read; if it is, an undefined value will be read.

PBDDR is initialized to H'00 by a power-on reset and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. The OPE bit in SBYCR is used to select whether the address output pins retain their output state or become high-impedance when a transition is made to software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Modes 4 and 5
 The corresponding port B pins are address outputs irrespective of the value of the PBDDR bits.

Mode 6
 Setting a PBDDR bit to 1 makes the corresponding port B pin an address output, while clearing the bit to 0 makes the pin an input port.

Mode 7
 Setting a PBDDR bit to 1 makes the corresponding port B pin an output port, while clearing the bit to 0 makes the pin an input port.

Port B Data Register (PBDR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PB7DR	PB6DR	PB5DR	PB4DR	PB3DR	PB2DR	PB1DR	PB0DR
Initial va	ılue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PBDR is an 8-bit readable/writable register that stores output data for the port B pins (PB_7 to PB_0). PBDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port B Register (PORTB) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PB7	PB6	PB5	PB4	PB3	PB2	PB1	PB0
Initial va	alue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins PB, to PB,

PORTB is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port B pins (PB₇ to PB₀) must always be performed on PBDR.

If a port B read is performed while PBDDR bits are set to 1, the PBDR values are read. If a port B read is performed while PBDDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTB contents are determined by the pin states, as PBDDR and PBDR are initialized. PORTB retains its prior state after a manual reset*, and in software standby mode.

Port B MOS Pull-Up Control Register (PBPCR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PB7PCR	PB6PCR	PB5PCR	PB4PCR	PB3PCR	PB2PCR	PB1PCR	PB0PCR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PBPCR is an 8-bit readable/writable register that controls the MOS input pull-up function incorporated into port B on an individual bit basis.

When a PBDDR bit is cleared to 0 (input port setting) in mode 6 or 7, setting the corresponding PBPCR bit to 1 turns on the MOS input pull-up for the corresponding pin.

PBPCR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

9.9.3 Pin Functions

Modes 4 and 5: In modes 4 and 5, port B pins are automatically designated as address outputs.

Port B pin functions in modes 4 and 5 are shown in figure 9-12.

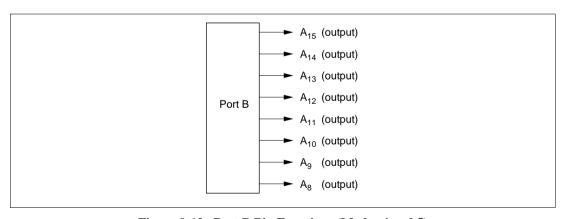


Figure 9-12 Port B Pin Functions (Modes 4 and 5)

Mode 6 (on-chip ROM version only): In mode 6, port B pins function as address outputs or input ports. Input or output can be specified on an individual bit basis. Setting a PBDDR bit to 1 makes the corresponding port B pin an address output, while clearing the bit to 0 makes the pin an input port.

Port B pin functions in mode 6 are shown in figure 9-13.

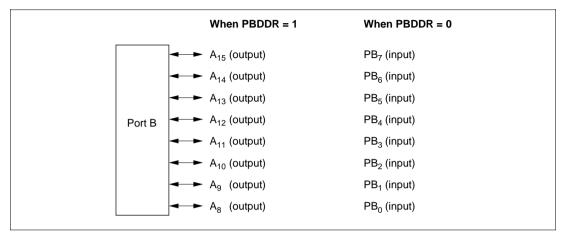


Figure 9-13 Port B Pin Functions (Modes 6)

Mode 7 (on-chip ROM version only): In mode 7, port B pins function as I/O ports. Input or output can be specified for each pin on an individual bit basis. Setting a PBDDR bit to 1 makes the corresponding port B pin an output port, while clearing the bit to 0 makes the pin an input port.

Port B pin functions in mode 7 are shown in figure 9-14.

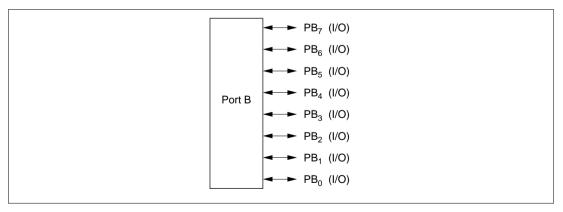


Figure 9-14 Port B Pin Functions (Mode 7)

9.9.4 MOS Input Pull-Up Function (On-Chip ROM Version Only)

Port B has a built-in MOS input pull-up function that can be controlled by software. This MOS input pull-up function can be used in modes 6 and 7, and can be specified as on or off on an individual bit basis.

When a PBDDR bit is cleared to 0 in mode 6 or 7, setting the corresponding PBPCR bit to 1 turns on the MOS input pull-up for that pin.

The MOS input pull-up function is in the off state after a power-on reset, and in hardware standby mode. The prior state is retained after a manual reset*, and in software standby mode.

Table 9-16 summarizes the MOS input pull-up states.

Table 9-16 MOS Input Pull-Up States (Port B)

Modes	Power-On Reset	Hardware Standby Mode		Software Standby Mode	In Other Operations
4, 5	OFF		OFF		_
6, 7	_		ON/OFF		

Legend:

OFF: MOS input pull-up is always off.

ON/OFF: On when PBDDR = 0 and PBPCR = 1; otherwise off.

9.10 Port C

9.10.1 Overview

Port C is an 8-bit I/O port. Port C has an address bus output function, and the pin functions change according to the operating mode.

Port C has a built-in MOS input pull-up function that can be controlled by software. (on-chip ROM version only)

Figure 9-15 shows the port C pin configuration.

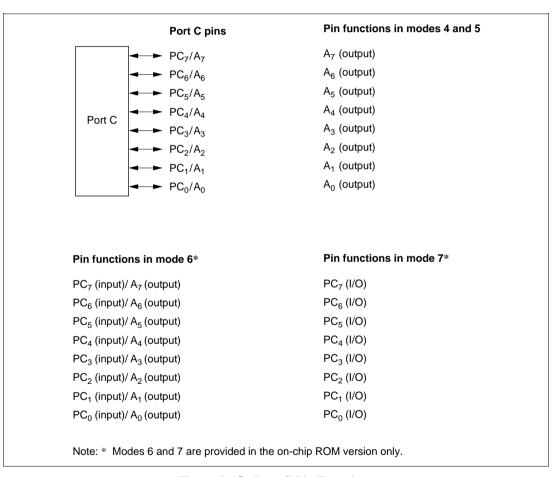


Figure 9-15 Port C Pin Functions

9.10.2 Register Configuration (On-Chip ROM Version Only)

Table 9-17 shows the port C register configuration.

Table 9-17 Port C Registers

Name	Abbreviation	R/W	Initial Value	Address *
Port C data direction register	PCDDR	W	H'00	H'FEBB
Port C data register	PCDR	R/W	H'00	H'FF6B
Port C register	PORTC	R	Undefined	H'FF5B
Port C MOS pull-up control register	PCPCR	R/W	H'00	H'FF72

Note: * Lower 16 bits of the address.

Port C Data Direction Register (PCDDR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PC7DDR	PC6DDR	PC5DDR	PC4DDR	PC3DDR	PC2DDR	PC1DDR	PC0DDR
Initial valu	ıe:	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

PCDDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port C. PCDDR cannot be read; if it is, an undefined value will be read.

PCDDR is initialized to H'00 by a power-on reset and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode. The OPE bit in SBYCR is used to select whether the address output pins retain their output state or become high-impedance when a transition is made to software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Modes 4 and 5
 The corresponding port C pins are address outputs irrespective of the value of the PCDDR bits.

Mode 6

Setting a PCDDR bit to 1 makes the corresponding port C pin an address output, while clearing the bit to 0 makes the pin an input port.

Mode 7

Setting a PCDDR bit to 1 makes the corresponding port C pin an output port, while clearing the bit to 0 makes the pin an input port.

Port C Data Register (PCDR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PC7DR	PC6DR	PC5DR	PC4DR	PC3DR	PC2DR	PC1DR	PC0DR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PCDR is an 8-bit readable/writable register that stores output data for the port C pins (PC₇ to PC₀).

PCDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port C Register (PORTC) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PC7	PC6	PC5	PC4	PC3	PC2	PC1	PC0
Initial va	alue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins PC, to PC.

PORTC is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port C pins (PC_7 to PC_0) must always be performed on PCDR.

If a port C read is performed while PCDDR bits are set to 1, the PCDR values are read. If a port C read is performed while PCDDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTC contents are determined by the pin states, as PCDDR and PCDR are initialized. PORTC retains its prior state after a manual reset*, and in software standby mode.

Port C MOS Pull-Up Control Register (PCPCR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PC7PCR	PC6PCR	PC5PCR	PC4PCR	PC3PCR	PC2PCR	PC1PCR	PC0PCR
Initial v	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PCPCR is an 8-bit readable/writable register that controls the MOS input pull-up function incorporated into port C on an individual bit basis.

When a PCDDR bit is cleared to 0 (input port setting) in mode 6 or 7, setting the corresponding PCPCR bit to 1 turns on the MOS input pull-up for the corresponding pin.

PCPCR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

9.10.3 Pin Functions

Modes 4 and 5: In modes 4 and 5, port C pins are automatically designated as address outputs.

Port C pin functions in modes 4 and 5 are shown in figure 9-16.

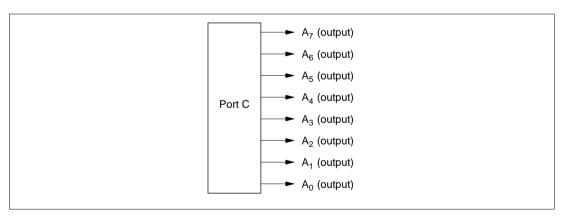


Figure 9-16 Port C Pin Functions (Modes 4 and 5)

Mode 6 (on-chip ROM version only): In mode 6, port C pins function as address outputs or input ports. Input or output can be specified on an individual bit basis. Setting a PCDDR bit to 1 makes the corresponding port C pin an address output, while clearing the bit to 0 makes the pin an input port.

Port C pin functions in mode 6 are shown in figure 9-17.

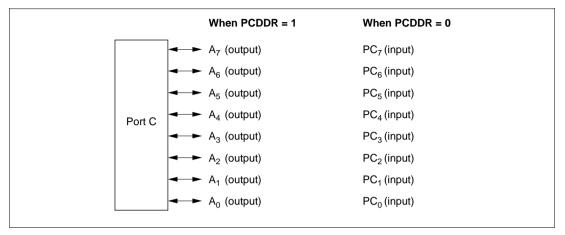


Figure 9-17 Port C Pin Functions (Mode 6)

Mode 7 (on-chip ROM version only): In mode 7, port C pins function as I/O ports. Input or output can be specified for each pin on an individual bit basis. Setting a PCDDR bit to 1 makes the corresponding port C pin an output port, while clearing the bit to 0 makes the pin an input port.

Port C pin functions in mode 7 are shown in figure 9-18.

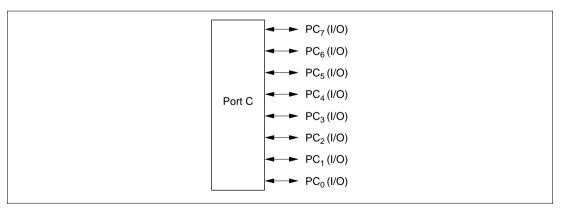


Figure 9-18 Port C Pin Functions (Mode 7)

9.10.4 MOS Input Pull-Up Function (On-Chip ROM Version Only)

Port C has a built-in MOS input pull-up function that can be controlled by software. This MOS input pull-up function can be used in modes 6 and 7, and can be specified as on or off on an individual bit basis.

When a PCDDR bit is cleared to 0 in mode 6 or 7, setting the corresponding PCPCR bit to 1 turns on the MOS input pull-up for that pin.

The MOS input pull-up function is in the off state after a power-on reset, and in hardware standby mode. The prior state is retained after a manual reset*, and in software standby mode.

Table 9-18 summarizes the MOS input pull-up states.

Table 9-18 MOS Input Pull-Up States (Port C)

Modes	Power-On Reset	Hardware Standby Mode		Software Standby Mode	In Other Operations
4, 5	OFF		OFF		_
6, 7	_		ON/OFF		

Legend:

OFF: MOS input pull-up is always off.

ON/OFF: On when PCDDR = 0 and PCPCR = 1; otherwise off.

9.11 Port D

9.11.1 Overview

Port D is an 8-bit I/O port. Port D has a data bus I/O function, and the pin functions change according to the operating mode. In the H8S/2352, port D pins are dedicated data bus pins.

Port D has a built-in MOS input pull-up function that can be controlled by software. (on-chip ROM version only)

Figure 9-19 shows the port D pin configuration.

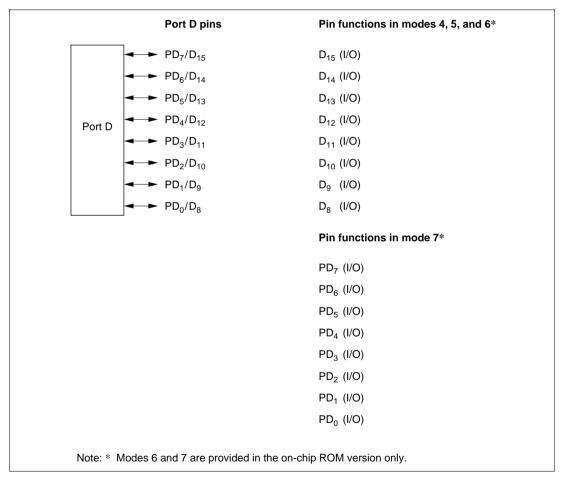


Figure 9-19 Port D Pin Functions

9.11.2 Register Configuration (On-Chip ROM Version Only)

Table 9-19 shows the port D register configuration.

Table 9-19 Port D Registers

Name	Abbreviation	R/W	Initial Value	Address *
Port D data direction register	PDDDR	W	H'00	H'FEBC
Port D data register	PDDR	R/W	H'00	H'FF6C
Port D register	PORTD	R	Undefined	H'FF5C
Port D MOS pull-up control register	PDPCR	R/W	H'00	H'FF73

Note: * Lower 16 bits of the address.

Port D Data Direction Register (PDDDR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PD7DDR	PD6DDR	PD5DDR	PD4DDR	PD3DDR	PD2DDR	PD1DDR	PD0DDR
Initial valu	ıe:	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

PDDDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port D. PDDDR cannot be read; if it is, an undefined value will be read..

PDDDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Modes 4, 5, and 6 The input/output direction specification by PDDDR is ignored, and port D is automatically designated for data I/O.

Mode 7 Setting a PDDDR bit to 1 makes the corresponding port D pin an output port, while clearing the bit to 0 makes the pin an input port.

Port D Data Register (PDDR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PD7DR	PD6DR	PD5DR	PD4DR	PD3DR	PD2DR	PD1DR	PD0DR
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PDDR is an 8-bit readable/writable register that stores output data for the port D pins (PD $_7$ to PD $_0$).

PDDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port D Register (PORTD) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PD7	PD6	PD5	PD4	PD3	PD2	PD1	PD0
Initial va	alue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins PD, to PD,.

PORTD is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port D pins (PD_7 to PD_0) must always be performed on PDDR.

If a port D read is performed while PDDDR bits are set to 1, the PDDR values are read. If a port D read is performed while PDDDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTD contents are determined by the pin states, as PDDDR and PDDR are initialized. PORTD retains its prior state after a manual reset*, and in software standby mode.

Port D MOS Pull-Up Control Register (PDPCR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PD7PCR	PD6PCR	PD5PCR	PD4PCR	PD3PCR	PD2PCR	PD1PCR	PD0PCR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PDPCR is an 8-bit readable/writable register that controls the MOS input pull-up function incorporated into port D on an individual bit basis.

When a PDDDR bit is cleared to 0 (input port setting) in mode 7, setting the corresponding PDPCR bit to 1 turns on the MOS input pull-up for the corresponding pin.

PDPCR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the on-chip ROM version version.

9.11.3 Pin Functions

Modes 4, 5 and 6*: In modes 4, 5, and 6, port D pins are automatically designated as data I/O pins.

Port D pin functions in modes 4, 5, and 6 are shown in figure 9-20.

Note: * Mode 6 is provided in the on-chip ROM version only.

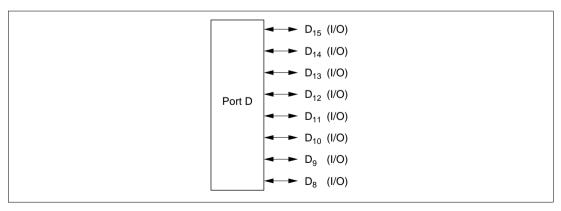


Figure 9-20 Port D Pin Functions (Modes 4, 5, and 6)

Modes 7 (on-chip ROM version only): In mode 7, port D pins function as I/O ports. Input or output can be specified for each pin on an individual bit basis. Setting a PDDDR bit to 1 makes the corresponding port D pin an output port, while clearing the bit to 0 makes the pin an input port.

Port D pin functions in mode 7 are shown in figure 9-21.

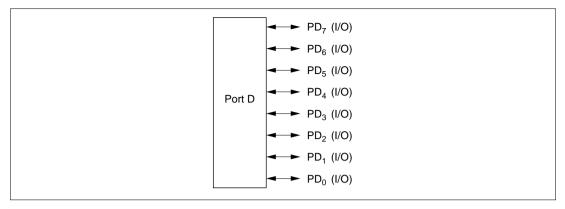


Figure 9-21 Port D Pin Functions (Mode 7)

9.11.4 MOS Input Pull-Up Function (On-Chip ROM Version Only)

Port D has a built-in MOS input pull-up function that can be controlled by software. This MOS input pull-up function can be used in mode 7, and can be specified as on or off on an individual bit basis.

When a PDDDR bit is cleared to 0 in mode 7, setting the corresponding PDPCR bit to 1 turns on the MOS input pull-up for that pin.

The MOS input pull-up function is in the off state after a power-on reset, and in hardware standby mode. The prior state is retained after a manual reset*, and in software standby mode.

Table 9-20 summarizes the MOS input pull-up states.

Table 9-20 MOS Input Pull-Up States (Port D)

Modes	Power-On Reset	Hardware Standby Mode		Software Standby Mode	In Other Operations
4 to 6	OFF		OFF		_
7	_		ON/OFF		

Legend:

OFF : MOS input pull-up is always off.

ON/OFF: On when PDDDR = 0 and PDPCR = 1; otherwise off.

9.12 Port E

9.12.1 Overview

Port E is an 8-bit I/O port. Port E has a data bus I/O function, and the pin functions change according to the operating mode and whether 8-bit or 16-bit bus mode is selected.

Port E has a built-in MOS input pull-up function that can be controlled by software. (on-chip ROM version only)

Figure 9-22 shows the port E pin configuration.

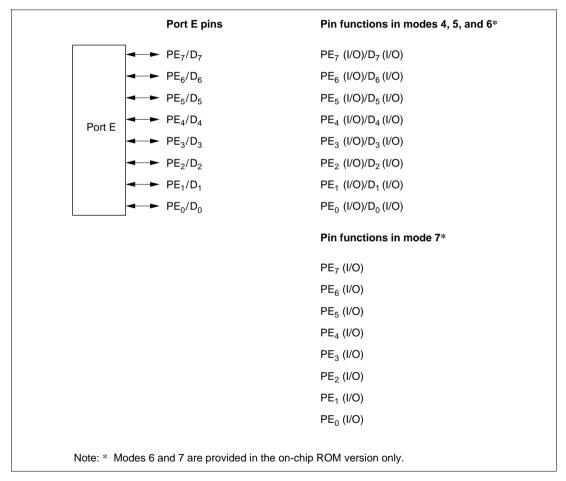


Figure 9-22 Port E Pin Functions

9.12.2 Register Configuration

Table 9-21 shows the port E register configuration.

Table 9-21 Port E Registers

Name	Abbreviation	R/W	Initial Value	Address*1
Port E data direction register	PEDDR	W	H'00	H'FEBD
Port E data register	PEDR	R/W	H'00	H'FF6D
Port E register	PORTE	R	Undefined	H'FF5D
Port E MOS pull-up control register*2	PEPCR	R/W	H'00	H'FF74

Notes: 1. Lower 16 bits of the address.

2. PEPCR settings are prohibited in the ROMless version.

Port E Data Direction Register (PEDDR)

Bit :	7	6	5	4	3	2	1	0
	PE7DDR	PE6DDR	PE5DDR	PE4DDR	PE3DDR	PE2DDR	PE1DDR	PE0DDR
Initial value :	0	0	0	0	0	0	0	0
R/W :	W	W	W	W	W	W	W	W

PEDDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port E. PEDDR cannot be read; if it is, an undefined value will be read.

PEDDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

• Modes 4, 5 and 6*

When 8-bit bus mode has been selected, port E pins function as I/O ports. Setting a PEDDR bit to 1 makes the corresponding port E pin an output port, while clearing the bit to 0 makes the pin an input port.

When 16-bit bus mode has been selected, the input/output direction specification by PEDDR is ignored, and port E is designated for data I/O.

For details of 8-bit and 16-bit bus modes, see section 6, Bus Controller.

Mode 7*

Setting a PEDDR bit to 1 makes the corresponding port E pin an output port, while clearing the bit to 0 makes the pin an input port.

Note: * Modes 6 and 7 are provided in the on-chip ROM version only.

Port E Data Register (PEDR)

Bit	:	7	6	5	4	3	2	1	0
		PE7DR	PE6DR	PE5DR	PE4DR	PE3DR	PE2DR	PE1DR	PE0DR
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PEDR is an 8-bit readable/writable register that stores output data for the port E pins (PE₇ to PE₀).

PEDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port E Register (PORTE)

Bit	:	7	6	5	4	3	2	1	0
		PE7	PE6	PE5	PE4	PE3	PE2	PE1	PE0
Initial va	ılue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins PE, to PE.

PORTE is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port E pins (PE_7 to PE_0) must always be performed on PEDR.

If a port E read is performed while PEDDR bits are set to 1, the PEDR values are read. If a port E read is performed while PEDDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTE contents are determined by the pin states, as PEDDR and PEDR are initialized. PORTE retains its prior state after a manual reset*, and in software standby mode.

Port E MOS Pull-Up Control Register (PEPCR) (On-Chip ROM Version Only)

Bit	:	7	6	5	4	3	2	1	0
		PE7PCR	PE6PCR	PE5PCR	PE4PCR	PE3PCR	PE2PCR	PE1PCR	PE0PCR
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PEPCR is an 8-bit readable/writable register that controls the MOS input pull-up function incorporated into port E on an individual bit basis.

When a PEDDR bit is cleared to 0 (input port setting) when 8-bit bus mode is selected in mode 4, 5, or 6, or in mode 7, setting the corresponding PEPCR bit to 1 turns on the MOS input pull-up for the corresponding pin.

PEPCR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

9.12.3 Pin Functions

Modes 4, 5, and 6*: In modes 4, 5, and 6, when 8-bit access is designated and 8-bit bus mode is selected, port E pins are automatically designated as I/O ports. Setting a PEDDR bit to 1 makes the corresponding port E pin an output port, while clearing the bit to 0 makes the pin an input port.

When 16-bit bus mode is selected, the input/output direction specification by PEDDR is ignored, and port E is designated for data I/O.

Port E pin functions in modes 4, 5, and 6 are shown in figure 9-23.

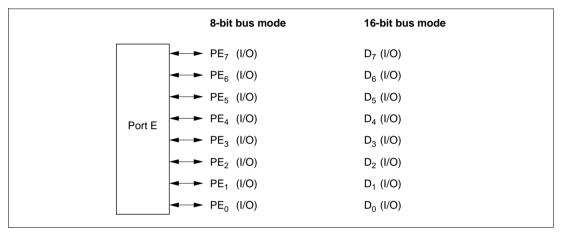


Figure 9-23 Port E Pin Functions (Modes 4, 5, and 6)

Mode 7*: In mode 7, port E pins function as I/O ports. Input or output can be specified for each pin on a bit-by-bit basis. Setting a PEDDR bit to 1 makes the corresponding port E pin an output port, while clearing the bit to 0 makes the pin an input port.

Note: * Modes 6 and 7 are provided in the on-chip ROM version only.

Port E pin functions in mode 7 are shown in figure 9-24.

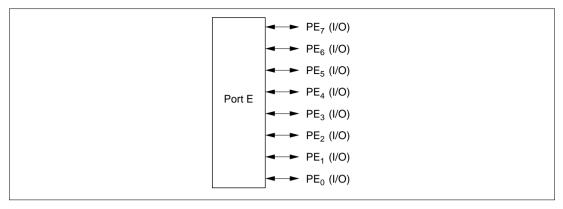


Figure 9-24 Port E Pin Functions (Mode 7)

9.12.4 MOS Input Pull-Up Function (On-Chip ROM Version Only)

Port E has a built-in MOS input pull-up function that can be controlled by software. This MOS input pull-up function can be used in modes 4, 5, and 6 when 8-bit bus mode is selected, or in mode 7, and can be specified as on or off on an individual bit basis.

When a PEDDR bit is cleared to 0 in mode 4, 5, or 6 when 8-bit bus mode is selected, or in mode 7, setting the corresponding PEPCR bit to 1 turns on the MOS input pull-up for that pin.

The MOS input pull-up function is in the off state after a power-on reset, and in hardware standby mode. The prior state is retained after a manual reset*, and in software standby mode.

Table 9-22 summarizes the MOS input pull-up states.

Table 9-22 MOS Input Pull-Up States (Port E)

Modes		Power-On Reset	Hardware Standby Mode	Manual Reset*	Software Standby Mode	In Other Operations
7		OFF		ON/OFF		
4 to 6	8-bit bus					
	16-bit bus			OFF		

Legend:

OFF : MOS input pull-up is always off.

ON/OFF: On when PEDDR = 0 and PEPCR = 1; otherwise off.

9.13 Port F

9.13.1 Overview

Port F is an 8-bit I/O port. Port F pins also function as bus control signal input/output pins $(\overline{AS}, \overline{RD}, \overline{HWR}, \overline{LWR}, \overline{LCAS}, \overline{WAIT}, \overline{BREQO}, \overline{BREQ}, \text{ and } \overline{BACK})$ and the system clock (\emptyset) output pin.

Figure 9-25 shows the port F pin configuration.

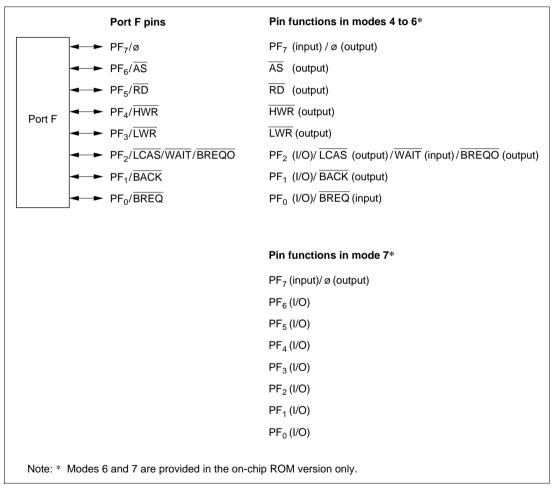


Figure 9-25 Port F Pin Functions

9.13.2 Register Configuration

Table 9-23 shows the port F register configuration.

Table 9-23 Port F Registers

Name	Abbreviation	R/W	Initial Value	Address *1
Port F data direction register	PFDDR	W	H'80/H'00*2	H'FEBE
Port F data register	PFDR	R/W	H'00	H'FF6E
Port F register	PORTF	R	Undefined	H'FF5E

Notes: 1. Lower 16 bits of the address.

2. Initial value depends on the mode.

Port F Data Direction Register (PFDDR)

Bit	:	7	6	5	4	3	2	1	0
		PF7DDR	PF6DDR	PF5DDR	PF4DDR	PF3DDR	PF2DDR	PF1DDR	PF0DDR
Modes 4, 5,	6								
Initial valu	e:	1	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W
Mode 7									
Initial valu	e:	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

PFDDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port F. PFDDR cannot be read; if it is, an undefined value will be read.

PFDDR is initialized by a power-on reset, and in hardware standby mode, to H'80 in modes 4, 5, and 6, and to H'00 in mode 7. It retains its prior state after a manual reset*, and in software standby mode. The OPE bit in SBYCR is used to select whether the bus control output pins retain their output state or become high-impedance when a transition is made to software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Modes 4, 5, and 6*

Pin PF₇ functions as the \emptyset output pin when the corresponding PFDDR bit is set to 1, and as an input port when the bit is cleared to 0.

The input/output direction specified by PFDDR is ignored for pins PF_6 to PF_3 , which are automatically designated as bus control outputs (\overline{AS} , \overline{RD} , \overline{HWR} , and \overline{LWR}).

Pins PF_2 to PF_0 are designated as bus control input/output pins (\overline{LCAS} , \overline{WAIT} , \overline{BREQO} , \overline{BACK} , \overline{BREQ}) by means of bus controller settings. At other times, setting a PFDDR bit to 1 makes the corresponding port F pin an output port, while clearing the bit to 0 makes the pin an input port.

Mode 7*

Setting a PFDDR bit to 1 makes the corresponding port F pin PF_6 to PF_0 an output port, or in the case of pin PF_7 , the \emptyset output pin. Clearing the bit to 0 makes the pin an input port.

Note: * Modes 6 and 7 are provided in the on-chip ROM version only.

Port F Data Register (PFDR)

Bit	:	7	6	5	4	3	2	1	0
		PF7DR	PF6DR	PF5DR	PF4DR	PF3DR	PF2DR	PF1DR	PF0DR
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

PFDR is an 8-bit readable/writable register that stores output data for the port F pins (PF₇ to PF₀).

PFDR is initialized to H'00 by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port F Register (PORTF)

Bit	:	7	6	5	4	3	2	1	0
		PF7	PF6	PF5	PF4	PF3	PF2	PF1	PF0
Initial va	lue :	*	*	*	*	*	*	*	*
R/W	:	R	R	R	R	R	R	R	R

Note: * Determined by state of pins PF₇ to PF₀.

PORTF is an 8-bit read-only register that shows the pin states. Writing of output data for the port F pins (PF_7 to PF_0) must always be performed on PFDR.

If a port F read is performed while PFDDR bits are set to 1, the PFDR values are read. If a port F read is performed while PFDDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTF contents are determined by the pin states, as PFDDR and PFDR are initialized. PORTF retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

9.13.3 Pin Functions

Port F pins also function as bus control signal input/output pins $(\overline{AS}, \overline{RD}, \overline{HWR}, \overline{LWR}, \overline{LCAS}, \overline{WAIT}, \overline{BREQO}, \overline{BREQ}, \text{ and } \overline{BACK})$ and the system clock (\emptyset) output pin. The pin functions differ between modes 4, 5, and 6, and mode 7. Port F pin functions are shown in table 9-24.

Table 9-24 Port F Pin Functions

Pin	Selection Meth	nod and Pin Function	ıs	
PF ₇ /ø	The pin function	n is switched as showr	n below according to	bit PF7DDR.
	PF7DDR	0		1
	Pin function	PF ₇ input pi	n	ø output pin
PF ₆ /AS	The pin function	n is switched as showr R.	n below according to	the operating mode
	Operating Mode	Modes 4, 5, 6*	Mod	de 7*
	PF6DDR	_	0	1
	Pin function	AS output pin	PF ₆ input pin	PF ₆ output pin
PF₅/RD	and bit PF5DDF Operating Mode	n is switched as showr R. Modes 4, 5, 6*		de 7*
	PF5DDR		0	1
	Pin function	RD output pin	PF ₅ input pin	PF₅ output pin
PF ₄ /HWR	The pin function	n is switched as showr R.	n below according to	the operating mod
	Operating Mode	Modes 4, 5, 6*	Mod	de 7*
	PF4DDR	_	0	1

HWR output pin

Pin function

PF₄ input pin

PF₄ output pin

Pin

Selection Method and Pin Functions

PF₃/LWR

The pin function is switched as shown below according to the operating mode and bit PF3DDR.

Operating Mode	Modes 4, 5, 6*	Mod	le 7*
PF3DDR	_	0	1
Pin function	LWR output pin	PF ₃ input pin	PF ₃ output pin

PF₂/LCAS/WAIT/ BREQO

The pin function is switched as shown below according to the combination of the operating mode, and bits RMTS2 to RMTS0, LCASS, BREQOE, WAITE, ABW5 to ABW2, and PF2DDR.

Operating Mode		Мо		Mode 7*			
LCASS	0*1			1		_	
BREQOE		0 1			1	_	
WAITE			0	1		_	
PF2DDR		0	1	_		0	1
Pin function	LCAS	PF ₂	PF ₂	WAIT	BREQO	PF ₂	PF ₂
	output pin	2 2			output pin	input pin	output pin

Note: 1. Only in DRAM space 16-bit access in modes 4 to 6 when RMTS2 to RMTS0 = B'001 to B'011.

$\mathsf{PF}_1/\overline{\mathsf{BACK}}$

The pin function is switched as shown below according to the combination of the operating mode, and bits BRLE and PF1DDR.

Operating Mode	N	/lodes 4, 5, 6	Mod	e 7*		
BRLE	()	1	_		
PF1DDR	0	1	_	0 1		
Pin function	PF ₁	PF ₁	BACK	PF ₁	PF ₁	
	input pin	output pin	output pin	input pin	output pin	

D	i	n
_		

Selection Method and Pin Functions

PF₀/BREQ

The pin function is switched as shown below according to the combination of the operating mode, and bits BRLE and PF0DDR.

Operating Mode	N	лоdes 4, 5, 6	Mode 7*		
BRLE	()	1	_	
PF0DDR	0	1	_	0	1
Pin function	PF₀ input pin	PF₀ output pin	BREQ input pin	PF₀ input pin	PF ₀ output pin

Note: *Modes 6 and 7 are provided in the on-chip ROM version only.

9.14 Port G

9.14.1 Overview

Port G is a 5-bit I/O port. Port G pins also function as bus control signal output pins ($\overline{CS0}$ to $\overline{CS3}$, and \overline{CAS}).

Figure 9-26 shows the port G pin configuration.

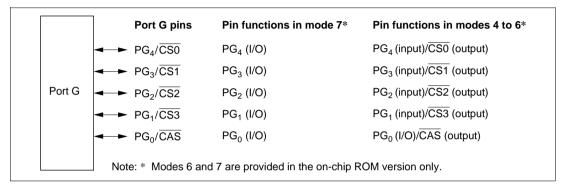


Figure 9-26 Port G Pin Functions

9.14.2 Register Configuration

Table 9-25 shows the port G register configuration.

Table 9-25 Port G Registers

Name	Abbreviation	R/W	Initial Value*2	Address*1
Port G data direction register	PGDDR	W	H'10/H'00*3	H'FEBF
Port G data register	PGDR	R/W	H'00	H'FF6F
Port G register	PORTG	R	Undefined	H'FF5F

Notes: 1. Lower 16 bits of the address.

- 2. Value of bits 4 to 0.
- 3. Initial value depends on the mode.

Port G Data Direction Register (PGDDR)

Bit :	7	6	5	4	3	2	1	0
	_	_		PG4DDR	PG3DDR	PG2DDR	PG1DDR	PG0DDR
Modes 4, 5								_
Initial value:	Undefined	Undefined	Undefined	1	0	0	0	0
R/W :	_		_	W	W	W	W	W
Mods 6, 7								
Initial value:	Undefined	Undefined	Undefined	0	0	0	0	0
R/W :	_	_	_	W	W	W	W	W

PGDDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port G. PGDDR cannot be read, and bits 7 to 5 are reserved. If PGDDR is read, an undefined value will be read.

The PG4DDR bit is initialized by a power-on reset and in hardware standby mode, to 1 in modes 4 and 5, and to 0 in modes 6 and 7. It retains its prior state after a manual reset* and in software standby mode. The OPE bit in SBYCR is used to select whether the bus control output pins retain their output state or become high-impedance when a transition is made to software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

- Modes 7*
 - Setting a PGDDR bit to 1 makes the corresponding port G pin an output port, while clearing the bit to 0 makes the pin an input port.
- Modes 4, 5, and 6*

Pins PG_4 to PG_1 function as bus control output pins ($\overline{CS0}$ to $\overline{CS3}$) when the corresponding PGDDR bits are set to 1, and as input ports when the bits are cleared to 0.

Pin PG_0 functions as the \overline{CAS} output pin when DRAM interface is designated. Otherwise, setting the corresponding PGDDR bit to 1 makes the pin an output port, while clearing the bit to 0 makes the pin an input port. For details of the DRAM interfaces, see section 6, Bus Controller.

Note: * Modes 6 and 7 are provided in the on-chip ROM version only.

Port G Data Register (PGDR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	PG4DR	PG3DR	PG2DR	PG1DR	PG0DR
Initia	l value :	Undefined	Undefined	Undefined	0	0	0	0	0
R/W	:	_	_	_	R/W	R/W	R/W	R/W	R/W

PGDR is an 8-bit readable/writable register that stores output data for the port G pins (PG₄ to PG₀).

Bits 7 to 5 are reserved; they return an undetermined value if read, and cannot be modified.

PGDR is initialized to H'00 (bits 4 to 0) by a power-on reset, and in hardware standby mode. It retains its prior state after a manual reset*, and in software standby mode.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

Port G Register (PORTG)

Bit :	7	6	5	4	3	2	1	0	
	_	_	_	PG4	PG3	PG2	PG1	PG0	
Initial value:	Undefined	Undefined	Undefined	*	*	*	*	*	
R/W :	_	_	_	R	R	R	R	R	

Note: * Determined by state of pins PG₄ to PG₀.

PORTG is an 8-bit read-only register that shows the pin states. It cannot be written to. Writing of output data for the port G pins (PG_4 to PG_0) must always be performed on PGDR.

Bits 7 to 5 are reserved; they return an undetermined value if read, and cannot be modified.

If a port G read is performed while PGDDR bits are set to 1, the PGDR values are read. If a port G read is performed while PGDDR bits are cleared to 0, the pin states are read.

After a power-on reset and in hardware standby mode, PORTG contents are determined by the pin states, as PGDDR and PGDR are initialized. PORTG retains its prior state after a manual reset*, and in software standby mode.

9.14.3 Pin Functions

Port G pins also function as bus control signal output pins ($\overline{CS0}$ to $\overline{CS3}$, and \overline{CAS}). The pin functions are different in mode 7, and modes 4 to 6. Port G pin functions are shown in table 9-26.

Table 9-26 Port G Pin Functions

and bit PG4DDR. Operating Mode Modes 4, 5, 6* Mode 7* PG4DDR 0 1 0 1 Pin function PG4 input pin CS0 output pin PG4 input pin PG4 output pin PG5 output pin PG5 output pin PG5 output pin PG5 output pin PG5 output pin PG5 output pin PG5 output pin PG5 output pin PG5 output pin PG5 input pin PG5 output pin PG5 output pin PG5 input pin PG5 output pin PG5 input pin PG5 output pin PG5 output pin PG5 input pin PG5 output pi	1 able 9-20 Pol	rt G Pin Functions	•							
and bit PG4DDR. Operating Mode Modes 4, 5, 6* Mode 7* PG4DDR 0 1 0 1 Pin function PG4 input pin CS0 output pin PG4 input pin PG4 output pin PG3/CS1 The pin function is switched as shown below according to the operating mode and bit PG3DDR. Operating Mode Mode 7* Modes 4 to 6* PG3DDR 0 1 0 1 Pin function PG3 input pin PG3 output pin PG3 input pin CS1 output pin PG4/CS2 The pin function is switched as shown below according to the operating mode and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6* PG2/CS2 The pin function is switched as shown below according to the operating mode and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6*	Pin	Selection Meth	od and Pin Fur	nctions						
Mode Modes 4, 5, 6* Mode 7* PG4DDR 0 1 0 1 Pin function PG4 input pin CSO output pin PG4 input pin PG4 output pin PG3/CS1 The pin function is switched as shown below according to the operating mode and bit PG3DDR. Operating Mode Mode 7* Modes 4 to 6* PG3DDR 0 1 0 1 Pin function PG3 input pin PG3 output pin PG3 input pin CS1 output pin PG4 input pin PG5 input pin CS1 output pin PG6 input PG₄/CS0	The pin function is switched as shown below according to the operating mode and bit PG4DDR.									
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			Modes	4, 5, 6*	Mode 7*					
$PG_{3}/\overline{CS1} \qquad \begin{array}{c ccccccccccccccccccccccccccccccccccc$		PG4DDR	0	1	0	1				
and bit PG3DDR. Operating Mode Mode 7* Modes 4 to 6* PG3DDR 0 1 0 1 Pin function PG3 input pin PG3 output pin PG3 input pin CS1 output pin PG2/CS2 The pin function is switched as shown below according to the operating mode and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6*		Pin function	PG ₄ input pin	CS0 output pin	PG₄ input pin	PG ₄ output pin				
and bit PG3DDR. Operating Mode Mode 7* Modes 4 to 6* PG3DDR 0 1 0 1 Pin function PG3 input pin PG3 output pin PG3 input pin CS1 output pin PG2/CS2 The pin function is switched as shown below according to the operating mode and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6*										
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	PG ₃ /CS1	The pin function is switched as shown below according to the operating mode and bit PG3DDR.								
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			Mod	le 7*	Modes 4 to 6*					
PG ₂ /CS2 The pin function is switched as shown below according to the operating mode and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6*		PG3DDR	0	1	0	1				
and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6*		Pin function	PG ₃ input pin	PG ₃ output pin	PG ₃ input pin	CS1 output pin				
and bit PG2DDR. Operating Mode Mode 7* Modes 4 to 6*										
Mode Mode 7* Modes 4 to 6*	PG ₂ /CS2	The pin function is switched as shown below according to the operating mode and bit PG2DDR.								
PG2DDR 0 1 0 1			Mod	le 7*	Modes	4 to 6*				
		PG2DDR	0	1	0	1				
Pin function PG ₂ input pin PG ₂ output pin PG ₂ input pin CS2 output pin		Pin function	PG ₂ input pin	PG ₂ output pin	PG ₂ input pin	CS2 output pin				

Pin Selection Method and Pin Functions

PG₁/CS3

The pin function is switched as shown below according to the operating mode and bit PG1DDR.

Operating Mode	Mod	le 7*	Modes	4 to 6*
PG1DDR	0	1	0	1
Pin function	PG₁ input pin	PG₁ output pin	PG₁ input pin	CS3 output pin

PG₀/CAS

The pin function is switched as shown below according to the combination of the operating mode and bits RMTS2 to RMTS0 and PG0DDR.

Operating Mode	Mode 7*		Modes 4 to 6*		
RMTS2 to RMTS0	_		B'000, B'100 to B'111		B'001 to B'011
PG0DDR	0	1	0	1	_
Pin function	PG₀ input pin	PG₀ output pin	PG₀ input pin	PG₀ output pin	CAS output

Note: * Modes 6 and 7 are provided in the on-chip ROM version only.

Section 10 16-Bit Timer Pulse Unit (TPU)

10.1 Overview

The H8S/2357 Series has an on-chip 16-bit timer pulse unit (TPU) that comprises six 16-bit timer channels.

10.1.1 Features

- Maximum 16-pulse input/output
 - A total of 16 timer general registers (TGRs) are provided (four each for channels 0 and 3, and two each for channels 1, 2, 4, and 5), each of which can be set independently as an output compare/input capture register
 - TGRC and TGRD for channels 0 and 3 can also be used as buffer registers
- Selection of 8 counter input clocks for each channel
- The following operations can be set for each channel:
 - Waveform output at compare match: Selection of 0, 1, or toggle output
 - Input capture function: Selection of rising edge, falling edge, or both edge detection
 - Counter clear operation: Counter clearing possible by compare match or input capture
 - Synchronous operation: Multiple timer counters (TCNT) can be written to simultaneously
 - Simultaneous clearing by compare match and input capture possible
 - Register simultaneous input/output possible by counter synchronous operation
 - PWM mode: Any PWM output duty can be set
 - Maximum of 15-phase PWM output possible by combination with synchronous operation
- Buffer operation settable for channels 0 and 3
 - Input capture register double-buffering possible
 - Automatic rewriting of output compare register possible
- Phase counting mode settable independently for each of channels 1, 2, 4, and 5
 - Two-phase encoder pulse up/down-count possible
- Cascaded operation
 - Channel 2 (channel 5) input clock operates as 32-bit counter by setting channel 1 (channel
 4) overflow/underflow
- Fast access via internal 16-bit bus
 - Fast access is possible via a 16-bit bus interface

- 26 interrupt sources
 - For channels 0 and 3, four compare match/input capture dual-function interrupts and one overflow interrupt can be requested independently
 - For channels 1, 2, 4, and 5, two compare match/input capture dual-function interrupts, one overflow interrupt, and one underflow interrupt can be requested independently
- Automatic transfer of register data
 - Block transfer, 1-word data transfer, and 1-byte data transfer possible by data transfer controller (DTC) or DMA controller (DMAC) activation
- Programmable pulse generator (PPG) output trigger can be generated
 - Channel 0 to 3 compare match/input capture signals can be used as PPG output trigger
- A/D converter conversion start trigger can be generated
 - Channel 0 to 5 compare match A/input capture A signals can be used as A/D converter conversion start trigger
- Module stop mode can be set
 - As the initial setting, TPU operation is halted. Register access is enabled by exiting module stop mode.

Table 10-1 lists the functions of the TPU.

Table 10-1 TPU Functions

Item		Channel 0	Channel 1	Channel 2	Channel 3	Channel 4	Channel 5
Count clock		ø/1 ø/4 ø/16 ø/64 TCLKA TCLKB TCLKC	ø/1 ø/4 ø/16 ø/64 ø/256 TCLKA TCLKB	ø/1 ø/4 ø/16 ø/64 ø/1024 TCLKA TCLKB	ø/1 ø/4 ø/16 ø/64 ø/256 ø/1024 ø/4096 TCLKA	ø/1 ø/4 ø/16 ø/64 ø/1024 TCLKA TCLKC	ø/1 ø/4 ø/16 ø/64 ø/256 TCLKA TCLKC
General re	egisters	TGR0A TGR0B	TGR1A TGR1B	TGR2A TGR2B	TGR3A TGR3B	TGR4A TGR4B	TGR5A TGR5B
General re buffer regi		TGR0C TGR0D	_	_	TGR3C TGR3D	_	_
I/O pins		TIOCA0 TIOCB0 TIOCC0 TIOCD0	TIOCA1 TIOCB1	TIOCA2 TIOCB2	TIOCA3 TIOCB3 TIOCC3 TIOCD3	TIOCA4 TIOCB4	TIOCA5 TIOCB5
Counter cl function	ear	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture
Compare	0 output	0	0	0	0	0	0
match	1 output	0	0	0	0	0	0
output	Toggle output	0	0	0	0	0	0
Input captor function	Input capture function		0	0	0	0	0
Synchronous operation		0	0	0	0	0	0
PWM mod	PWM mode		0	0	0	0	0
Phase cou mode	Phase counting mode		0	0	_	0	0
Buffer ope	ration	0	_	_	0	_	_

Item	Channel 0	Channel 1	Channel 2	Channel 3	Channel 4	Channel 5
DMAC activation	TGR0A compare match or input capture	TGR1A compare match or input capture	TGR2A compare match or input capture	TGR3A compare match or input capture	TGR4A compare match or input capture	TGR5A compare match or input capture
DTC activation	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture	TGR compare match or input capture
A/D converter trigger	TGR0A compare match or input capture	TGR1A compare match or input capture	TGR2A compare match or input capture	TGR3A compare match or input capture	TGR4A compare match or input capture	TGR5A compare match or input capture
PPG trigger	TGR0A/ TGR0B compare match or input capture	TGR1A/ TGR1B compare match or input capture	TGR2A/ TGR2B compare match or input capture	TGR3A/ TGR3B compare match or input capture	_	_
Interrupt sources	Sources Compare match or input capture 0.6 Overflow	 Compare match or input capture 18 Overflow Underflow 	match or input Capture 2A Compare match or input Capture 2B Overflow	 Compare match or input capture 38 Compare 	match or input A capture 4A Compare match or input Capture 4B Overflow Underflow	 Compare match or input capture 5B Overflow

Legend

○ : Possible─ : Not possible

10.1.2 Block Diagram

Figure 10-1 shows a block diagram of the TPU.

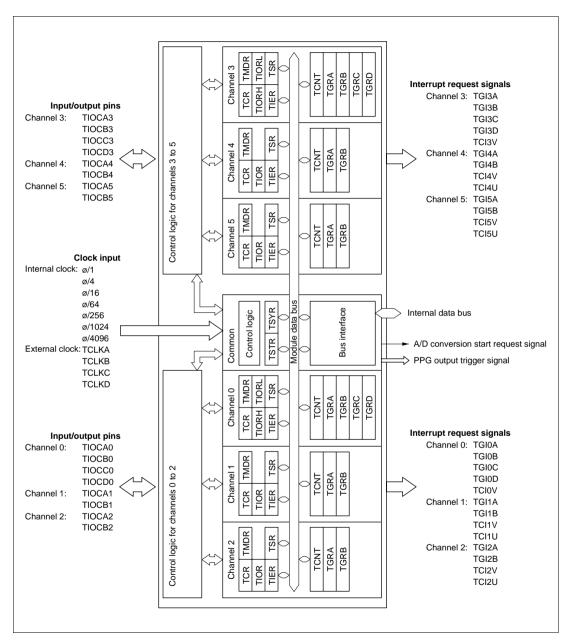


Figure 10-1 Block Diagram of TPU

10.1.3 Pin Configuration

Table 10-2 summarizes the TPU pins.

Table 10-2 TPU Pins

Channel	Name	Symbol	I/O	Function
All	Clock input A	TCLKA	Input	External clock A input pin (Channel 1 and 5 phase counting mode A phase input)
	Clock input B	TCLKB	Input	External clock B input pin (Channel 1 and 5 phase counting mode B phase input)
	Clock input C	TCLKC	Input	External clock C input pin (Channel 2 and 4 phase counting mode A phase input)
	Clock input D	TCLKD	Input	External clock D input pin (Channel 2 and 4 phase counting mode B phase input)
0	Input capture/out compare match A0	TIOCA0	I/O	TGR0A input capture input/output compare output/PWM output pin
	Input capture/out compare match B0	TIOCB0	I/O	TGR0B input capture input/output compare output/PWM output pin
	Input capture/out compare match C0	TIOCC0	I/O	TGR0C input capture input/output compare output/PWM output pin
	Input capture/out compare match D0	TIOCD0	I/O	TGR0D input capture input/output compare output/PWM output pin
1	Input capture/out compare match A1	TIOCA1	I/O	TGR1A input capture input/output compare output/PWM output pin
	Input capture/out compare match B1	TIOCB1	I/O	TGR1B input capture input/output compare output/PWM output pin
2	Input capture/out compare match A2	TIOCA2	I/O	TGR2A input capture input/output compare output/PWM output pin
	Input capture/out compare match B2	TIOCB2	I/O	TGR2B input capture input/output compare output/PWM output pin

Channel	Name	Symbol	I/O	Function
3	Input capture/out compare match A3	TIOCA3	I/O	TGR3A input capture input/output compare output/PWM output pin
	Input capture/out compare match B3	TIOCB3	I/O	TGR3B input capture input/output compare output/PWM output pin
	Input capture/out compare match C3	TIOCC3	I/O	TGR3C input capture input/output compare output/PWM output pin
	Input capture/out compare match D3	TIOCD3	I/O	TGR3D input capture input/output compare output/PWM output pin
4	Input capture/out compare match A4	TIOCA4	I/O	TGR4A input capture input/output compare output/PWM output pin
	Input capture/out compare match B4	TIOCB4	I/O	TGR4B input capture input/output compare output/PWM output pin
5	Input capture/out compare match A5	TIOCA5	I/O	TGR5A input capture input/output compare output/PWM output pin
	Input capture/out compare match B5	TIOCB5	I/O	TGR5B input capture input/output compare output/PWM output pin

10.1.4 Register Configuration

Table 10-3 summarizes the TPU registers.

Table 10-3 TPU Registers

Channel	Name	Abbreviation	R/W	Initial Value	Address *1
0	Timer control register 0	TCR0	R/W	H'00	H'FFD0
	Timer mode register 0	TMDR0	R/W	H'C0	H'FFD1
	Timer I/O control register 0H	TIOR0H	R/W	H'00	H'FFD2
	Timer I/O control register 0L	TIOR0L	R/W	H'00	H'FFD3
	Timer interrupt enable register 0	TIER0	R/W	H'40	H'FFD4
	Timer status register 0	TSR0	R/(W)*2	H'C0	H'FFD5
	Timer counter 0	TCNT0	R/W	H'0000	H'FFD6
	Timer general register 0A	TGR0A	R/W	H'FFFF	H'FFD8
	Timer general register 0B	TGR0B	R/W	H'FFFF	H'FFDA
	Timer general register 0C	TGR0C	R/W	H'FFFF	H'FFDC
	Timer general register 0D	TGR0D	R/W	H'FFFF	H'FFDE
1	Timer control register 1	TCR1	R/W	H'00	H'FFE0
	Timer mode register 1	TMDR1	R/W	H'C0	H'FFE1
	Timer I/O control register 1	TIOR1	R/W	H'00	H'FFE2
	Timer interrupt enable register 1	TIER1	R/W	H'40	H'FFE4
	Timer status register 1	TSR1	R/(W) *2	H'C0	H'FFE5
	Timer counter 1	TCNT1	R/W	H'0000	H'FFE6
	Timer general register 1A	TGR1A	R/W	H'FFFF	H'FFE8
	Timer general register 1B	TGR1B	R/W	H'FFFF	H'FFEA
2	Timer control register 2	TCR2	R/W	H'00	H'FFF0
	Timer mode register 2	TMDR2	R/W	H'C0	H'FFF1
	Timer I/O control register 2	TIOR2	R/W	H'00	H'FFF2
	Timer interrupt enable register 2	TIER2	R/W	H'40	H'FFF4
	Timer status register 2	TSR2	R/(W) *2	H'C0	H'FFF5
	Timer counter 2	TCNT2	R/W	H'0000	H'FFF6
	Timer general register 2A	TGR2A	R/W	H'FFFF	H'FFF8
	Timer general register 2B	TGR2B	R/W	H'FFFF	H'FFFA

Channel	Name	Abbreviation	R/W	Initial Value	Address*1
3	Timer control register 3	TCR3	R/W	H'00	H'FE80
	Timer mode register 3	TMDR3	R/W	H'C0	H'FE81
	Timer I/O control register 3H	TIOR3H	R/W	H'00	H'FE82
	Timer I/O control register 3L	TIOR3L	R/W	H'00	H'FE83
	Timer interrupt enable register 3	TIER3	R/W	H'40	H'FE84
	Timer status register 3	TSR3	R/(W)*2	H'C0	H'FE85
	Timer counter 3	TCNT3	R/W	H'0000	H'FE86
	Timer general register 3A	TGR3A	R/W	H'FFFF	H'FE88
	Timer general register 3B	TGR3B	R/W	H'FFFF	H'FE8A
	Timer general register 3C	TGR3C	R/W	H'FFFF	H'FE8C
	Timer general register 3D	TGR3D	R/W	H'FFFF	H'FE8E
4	Timer control register 4	TCR4	R/W	H'00	H'FE90
	Timer mode register 4	TMDR4	R/W	H'C0	H'FE91
	Timer I/O control register 4	TIOR4	R/W	H'00	H'FE92
	Timer interrupt enable register 4	TIER4	R/W	H'40	H'FE94
	Timer status register 4	TSR4	R/(W) *2	H'C0	H'FE95
	Timer counter 4	TCNT4	R/W	H'0000	H'FE96
	Timer general register 4A	TGR4A	R/W	H'FFFF	H'FE98
	Timer general register 4B	TGR4B	R/W	H'FFFF	H'FE9A
5	Timer control register 5	TCR5	R/W	H'00	H'FEA0
	Timer mode register 5	TMDR5	R/W	H'C0	H'FEA1
	Timer I/O control register 5	TIOR5	R/W	H'00	H'FEA2
	Timer interrupt enable register 5	TIER5	R/W	H'40	H'FEA4
	Timer status register 5	TSR5	R/(W) *2	H'C0	H'FEA5
	Timer counter 5	TCNT5	R/W	H'0000	H'FEA6
	Timer general register 5A	TGR5A	R/W	H'FFFF	H'FEA8
	Timer general register 5B	TGR5B	R/W	H'FFFF	H'FEAA
All	Timer start register	TSTR	R/W	H'00	H'FFC0
	Timer synchro register	TSYR	R/W	H'00	H'FFC1
	Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address.

2. Can only be written with 0 for flag clearing.

10.2 Register Descriptions

10.2.1 Timer Control Register (TCR)

Channel 0: TCR0
Channel 3: TCR3

0 Bit 7 6 5 4 3 2 1 CCLR2 CCLR1 CCLR0 CKEG1 CKEG0 TPSC2 TPSC1 TPSC0 Initial value: 0 0 0 0 0 0 0 0 R/W R/W R/W R/W R/W R/W R/W R/W R/W

Channel 1: TCR1
Channel 2: TCR2
Channel 4: TCR4
Channel 5: TCR5

Bit	:	7	6	5	4	3	2	1	0
			CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0
Initial value	е:	0	0	0	0	0	0	0	0
R/W	:	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W

The TCR registers are 8-bit registers that control the TCNT channels. The TPU has six TCR registers, one for each of channels 0 to 5. The TCR registers are initialized to H'00 by a reset, and in hardware standby mode.

TCR register settings should be made only when TCNT operation is stopped.

Bits 7, 6, 5—Counter Clear 2, 1, and 0 (CCLR2, CCLR1, CCLR0): These bits select the TCNT counter clearing source.

Channel	Bit 7 CCLR2	Bit 6 CCLR1	Bit 5 CCLR0	Description
0, 3	0	0	0	TCNT clearing disabled (Initial value)
			1 TCNT cleared by TGRA compare match capture	
		1	0	TCNT cleared by TGRB compare match/input capture
			1	TCNT cleared by counter clearing for another channel performing synchronous clearing/ synchronous operation *1
	1	0	0	TCNT clearing disabled
			1	TCNT cleared by TGRC compare match/input capture *2
		1	0	TCNT cleared by TGRD compare match/input capture *2
			1	TCNT cleared by counter clearing for another channel performing synchronous clearing/ synchronous operation *1

Channel	Bit 7 Reserved	Bit 6 *3 CCLR1	Bit 5 CCLR0	Description
1, 2, 4, 5	0	0	0	TCNT clearing disabled (Initial value)
			1	TCNT cleared by TGRA compare match/input capture
		1	0	TCNT cleared by TGRB compare match/input capture
			1	TCNT cleared by counter clearing for another channel performing synchronous clearing/ synchronous operation *1

Notes: 1. Synchronous operation setting is performed by setting the SYNC bit in TSYR to 1.

- 2. When TGRC or TGRD is used as a buffer register, TCNT is not cleared because the buffer register setting has priority, and compare match/input capture does not occur.
- 3. Bit 7 is reserved in channels 1, 2, 4, and 5. It is always read as 0 and cannot be modified.

Bits 4 and 3—Clock Edge 1 and 0 (CKEG1, CKEG0): These bits select the input clock edge. When the input clock is counted using both edges, the input clock period is halved (e.g. $\emptyset/4$ both edges = $\emptyset/2$ rising edge). If phase counting mode is used on channels 1, 2, 4, and 5, this setting is ignored and the phase counting mode setting has priority.

Bit 4 CKEG1	Bit 3 CKEG0	Description	
0	0	Count at rising edge	(Initial value)
	1	Count at falling edge	
1	_	Count at both edges	

Note: Internal clock edge selection is valid when the input clock is Ø/4 or slower. This setting is ignored if the input clock is Ø/1, or when overflow/underflow of another channel is selected.

Bits 2, 1, and 0—Time Prescaler 2, 1, and 0 (TPSC2 to TPSC0): These bits select the TCNT counter clock. The clock source can be selected independently for each channel. Table 10-4 shows the clock sources that can be set for each channel.

Table 10-4 TPU Clock Sources

			1	Interna	al Cloc	k			Extern	al Clock		Overflow/ Underflow on Another
Channel	ø/1	ø/4	ø/16	ø/64	ø/256	ø/1024	ø/4096	TCLKA	TCLKB	TCLKC	TCLKD	Channel
0	0	0	\circ	\circ				0	0	0	0	
1	0	0	0	0	0			0	0			0
2	0	0	0	0		0		0	0	0		
3	0	0	0	0	0	0	0	0				
4	0	0	\circ	\circ		0		0		0		0
5	0	0	0	\circ	0			0		0	0	

Legend

SettingBlank : No setting

Channel	Bit 2 TPSC2	Bit 1 TPSC1	Bit 0 TPSC0	Description
0	0	0	0	Internal clock: counts on ø/1 (Initial value)
			1	Internal clock: counts on ø/4
		1	0	Internal clock: counts on ø/16
			1	Internal clock: counts on ø/64
	1	0	0	External clock: counts on TCLKA pin input
			1	External clock: counts on TCLKB pin input
		1	0	External clock: counts on TCLKC pin input
			1	External clock: counts on TCLKD pin input

Channel	Bit 2 TPSC2	Bit 1 TPSC1	Bit 0 TPSC0	Description
1	0	0	0	Internal clock: counts on ø/1 (Initial value)
			1	Internal clock: counts on ø/4
		1	0	Internal clock: counts on ø/16
			1	Internal clock: counts on ø/64
	1	0	0	External clock: counts on TCLKA pin input
			1	External clock: counts on TCLKB pin input
		1	0	Internal clock: counts on ø/256
			1	Counts on TCNT2 overflow/underflow

Note: This setting is ignored when channel 1 is in phase counting mode.

Channel	Bit 2 TPSC2	Bit 1 TPSC1	Bit 0 TPSC0	Description
2	0	0	0	Internal clock: counts on ø/1 (Initial value)
			1	Internal clock: counts on ø/4
		1	0	Internal clock: counts on ø/16
			1	Internal clock: counts on ø/64
	1	0	0	External clock: counts on TCLKA pin input
			1	External clock: counts on TCLKB pin input
		1	0	External clock: counts on TCLKC pin input
			1	Internal clock: counts on ø/1024

Note: This setting is ignored when channel 2 is in phase counting mode.

Channel	Bit 2 TPSC2	Bit 1 TPSC1	Bit 0 TPSC0	Description
3	0	0	0	Internal clock: counts on ø/1 (Initial value)
			1	Internal clock: counts on ø/4
		1	0	Internal clock: counts on ø/16
			1	Internal clock: counts on ø/64
	1	0	0	External clock: counts on TCLKA pin input
			1	Internal clock: counts on ø/1024
		1	0	Internal clock: counts on ø/256
			1	Internal clock: counts on ø/4096

Channel	Bit 2 TPSC2	Bit 1 TPSC1	Bit 0 TPSC0	Description
4	0	0	0	Internal clock: counts on ø/1 (Initial value)
			1	Internal clock: counts on ø/4
		1	0	Internal clock: counts on ø/16
			1	Internal clock: counts on ø/64
	1	0	0	External clock: counts on TCLKA pin input
			1	External clock: counts on TCLKC pin input
		1	0	Internal clock: counts on ø/1024
			1	Counts on TCNT5 overflow/underflow

Note: This setting is ignored when channel 4 is in phase counting mode.

Channel	Bit 2 TPSC2	Bit 1 TPSC1	Bit 0 TPSC0	Description
5	0	0	0	Internal clock: counts on ø/1 (Initial value)
			1	Internal clock: counts on ø/4
		1	0	Internal clock: counts on ø/16
			1	Internal clock: counts on ø/64
	1	0	0	External clock: counts on TCLKA pin input
			1	External clock: counts on TCLKC pin input
		1	0	Internal clock: counts on ø/256
			1	External clock: counts on TCLKD pin input

Note: This setting is ignored when channel 5 is in phase counting mode.

10.2.2 Timer Mode Register (TMDR)

Channel 0: TMDR0
Channel 3: TMDR3

Bit	:	7	6	5	4	3	2	1	0
		_	_	BFB	BFA	MD3	MD2	MD1	MD0
Initial valu	ie:	1	1	0	0	0	0	0	0
R/W	:	_	_	R/W	R/W	R/W	R/W	R/W	R/W

Channel 1: TMDR1
Channel 2: TMDR2
Channel 4: TMDR4
Channel 5: TMDR5

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	MD3	MD2	MD1	MD0
Initial value	:	1	1	0	0	0	0	0	0
R/W	:	_	_	_	_	R/W	R/W	R/W	R/W

The TMDR registers are 8-bit readable/writable registers that are used to set the operating mode for each channel. The TPU has six TMDR registers, one for each channel. The TMDR registers are initialized to H'C0 by a reset, and in hardware standby mode.

TMDR register settings should be made only when TCNT operation is stopped.

Bits 7 and 6—Reserved: These bits cannot be modified and are always read as 1.

Bit 5—Buffer Operation B (BFB): Specifies whether TGRB is to operate in the normal way, or TGRB and TGRD are to be used together for buffer operation. When TGRD is used as a buffer register, TGRD input capture/output compare is not generated.

In channels 1, 2, 4, and 5, which have no TGRD, bit 5 is reserved. It is always read as 0 and cannot be modified.

Bit 5		
BFB	Description	
0	TGRB operates normally	(Initial value)
1	TGRB and TGRD used together for buffer operation	

Bit 4—Buffer Operation A (BFA): Specifies whether TGRA is to operate in the normal way, or TGRA and TGRC are to be used together for buffer operation. When TGRC is used as a buffer register, TGRC input capture/output compare is not generated.

In channels 1, 2, 4, and 5, which have no TGRC, bit 4 is reserved. It is always read as 0 and cannot be modified.

Bit 4		
BFA	Description	
0	TGRA operates normally	(Initial value)
1	TGRA and TGRC used together for buffer operation	

Bits 3 to 0—Modes 3 to 0 (MD3 to MD0): These bits are used to set the timer operating mode.

Bit 3 MD3* ¹	Bit 2 MD2* ²	Bit 1 MD1	Bit 0 MD0	Description	
0	0	0	0	Normal operation	(Initial value)
			1	Reserved	
		1	0	PWM mode 1	
			1	PWM mode 2	
	1	0	0	Phase counting mode 1	
			1	Phase counting mode 2	
		1	0	Phase counting mode 3	
			1	Phase counting mode 4	
1	*	*	*	-	

*: Don't care

Notes: 1. MD3 is a reserved bit. In a write, it should always be written with 0.

2. Phase counting mode cannot be set for channels 0 and 3. In this case, 0 should always be written to MD2.

10.2.3 Timer I/O Control Register (TIOR)

Channel 0: TIOR0H
Channel 1: TIOR1
Channel 2: TIOR2
Channel 3: TIOR3H
Channel 4: TIOR4
Channel 5: TIOR5

Bit	:	7	6	5	4	3	2	1	0
		IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0
Initial va	lue :	0	0	0	0	0	0	0	0
R/W		R/W							

Channel 0: TIOR0L Channel 3: TIOR3L

Bit	:	7	6	5	4	3	2	1	0
		IOD3	IOD2	IOD1	IOD0	IOC3	IOC2	IOC1	IOC0
Initial value	: _	0	0	0	0	0	0	0	0
R/W	:	R/W							

Note: When TGRC or TGRD is designated for buffer operation, this setting is invalid and the register operates as a buffer register.

The TIOR registers are 8-bit registers that control the TGR registers. The TPU has eight TIOR registers, two each for channels 0 and 3, and one each for channels 1, 2, 4, and 5. The TIOR registers are initialized to H'00 by a reset, and in hardware standby mode.

Care is required since TIOR is affected by the TMDR setting. The initial output specified by TIOR is valid when the counter is stopped (the CST bit in TSTR is cleared to 0). Note also that, in PWM mode 2, the output at the point at which the counter is cleared to 0 is specified.

Bits 7 to 4— I/O Control B3 to B0 (IOB3 to IOB0) I/O Control D3 to D0 (IOD3 to IOD0):

Bits IOB3 to IOB0 specify the function of TGRB. Bits IOD3 to IOD0 specify the function of TGRD.

Bit 7 Bit 6 Bit 5 Bit 4

Channel	IOB3	IOB2	IOB1	IOB0	Description		
0	0	0	0	0	TGR0B is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
			1	0	–compare register	output	1 output at compare match
				1			Toggle output at compare match
		1	0	0	_	Output disabled	
				1	_	Initial output is 1	0 output at compare match
			1	0	_	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR0B is	Capture input	Input capture at rising edge
				1	input _capture	source is TIOCB0 pin	Input capture at falling edge
			1	*		ПОСВО РІП	Input capture at both edges
		1	*	*	_	Capture input source is channel 1/count clock	Input capture at TCNT1 count- up/count-down*1

Note: 1. When bits TPSC2 to TPSC0 in TCR1 are set to B'000 and Ø/1 is used as the TCNT1 count clock, this setting is invalid and input capture is not generated.

Channel	Bit 7 IOD3	Bit 6 IOD2	Bit 5 IOD1	Bit 4 IOD0	Description	on	
0	0	0	0	0	TGR0D is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
	compare output 1 0 register*2	1 output at compare match					
				1		Toggle output at compare match	
		1	1 Initial output is	Output disabled			
				1		Initial output is 1	0 output at compare match
			1	0	_	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR0D is	Capture input	Input capture at rising edge
	1 input source is capture TIOCD0 pin 1 * register*2		Input capture at falling edge				
			1	*	register*2	ПОСВО РІП	Input capture at both edges
		1	*	*		Capture input source is channel 1/count clock	Input capture at TCNT1 count-up/count-down*1

- Notes: 1. When bits TPSC2 to TPSC0 in TCR1 are set to B'000 and Ø/1 is used as the TCNT1 count clock, this setting is invalid and input capture is not generated.
 - 2. When the BFB bit in TMDR0 is set to 1 and TGR0D is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

Channel	Bit 7 IOB3	Bit 6 IOB2	Bit 5 IOB1	Bit 4 IOB0	Description	on	
1	0	0	0	0	TGR1B is	Output disabled	(Initial value)
	1 output Initial output is 0	0 output at compare match					
		compare output 1 0 register	output	1 output at compare match			
			1		Toggle output at compare match		
		1	0	0	_	Output disabled	
			1	Initial output is 1	0 output at compare match		
			1	0	_	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR1B is	Capture input	Input capture at rising edge
				1	input _capture	source is TIOCB1 pin	Input capture at falling edge
			1	*		Input capture at both edges	
		1	*	*	_	Capture input source is TGR0C compare match/ input capture	Input capture at generation of TGR0C compare match/input capture

Channel	Bit 7 IOB3	Bit 6 IOB2	Bit 5 IOB1	Bit 4 IOB0	Description	on	
2	0	0	0	0	TGR2B is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
			1	0	–compare register	output	1 output at compare match
				1	_		Toggle output at compare match
		1	0	0	_	Output disabled	
				1	_	Initial output is 1 output	0 output at compare match
			1	0	_		1 output at compare match
				1	_		Toggle output at compare match
	1	*	0	0	TGR2B is	Capture input	Input capture at rising edge
				1	input		Input capture at falling edge
			1	*	capture TIOCB2 pin register		Input capture at both edges

Channel	Bit 7 IOB3	Bit 6 IOB2	Bit 5 IOB1	Bit 4 IOB0	Description	on	
3	0	0	0	0	TGR3B is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
	compare output 1 0 register	output	1 output at compare match				
		1		Toggle output at compare match			
		1	0	0		Output disabled	
		1 Initial output is	Initial output is 1	0 output at compare match			
			1	0		output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR3B is	Capture input	Input capture at rising edge
				1	input _capture	source is TIOCB3 pin	Input capture at falling edge
			1	*	register	110000 ріп	Input capture at both edges
		1	*	*	_	Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/count-down*1

Note: 1. When bits TPSC2 to TPSC0 in TCR4 are set to B'000 and Ø/1 is used as the TCNT4 count clock, this setting is invalid and input capture is not generated.

Channel	Bit 7 IOD3	Bit 6 IOD2	Bit 5 IOD1	Bit 4 IOD0	Description	on	
3	0	0	0	0	TGR3D is	Output disabled	(Initial value)
	1 output Initial output is 0	0 output at compare match					
			1	0	-compare register*2		1 output at compare match
				1		Toggle output at compare match	
		1	0	0	=	Output disabled	
		1 Initial output is	Initial output is 1	0 output at compare match			
			1	0	_	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR3D is	Capture input	Input capture at rising edge
				1	input _capture	source is TIOCD3 pin	Input capture at falling edge
	1 * register* ²	Input capture at both edges					
		1	*	*	_	Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/count-down*1

- Notes: 1. When bits TPSC2 to TPSC0 in TCR4 are set to B'000 and ø/1 is used as the TCNT4 count clock, this setting is invalid and input capture is not generated.
 - 2. When the BFB bit in TMDR3 is set to 1 and TGR3D is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

Channel	Bit 7 IOB3	Bit 6 IOB2	Bit 5 IOB1	Bit 4 IOB0	Description	on	
4	0	0	0	0	TGR4B is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
1	0	compare register	output	1 output at compare match			
	1 0 0 Output disabled 1 Initial output is 1	Toggle output at compare match					
		Output disabled					
		Initial output is 1	0 output at compare match				
			1	0	_	output	1 output at compare match
				1			Toggle output at compare match
	1	0	0	0	TGR4B is	Capture input	Input capture at rising edge
				1	input	source is	Input capture at falling edge
	capture TIOCB4 pin 1 * register	посьч ріп	Input capture at both edges				
		1	*	*	_	Capture input source is TGR3C compare match/ input capture	Input capture at generation of TGR3C compare match/ input capture

Channel	Bit 7 IOB3	Bit 6 IOB2	Bit 5 IOB1	Bit 4 IOB0	Description	on	
5	0	0	0	0	TGR5B is	Output disabled	(Initial value)
				1	output compare	Initial output is 0	0 output at compare match
			1	0	register	output	1 output at compare match
				1	3		Toggle output at compare match
		1	0	0		Output disabled	
				1	-	Initial output is 1 output	0 output at compare match
			1	0	-		1 output at compare match
				1	_		Toggle output at compare match
	1	*	0	0	TGR5B is	Capture input	Input capture at rising edge
				1		source is TIOCB5 pin	Input capture at falling edge
			1	*	register	посьз ріп	Input capture at both edges

Bits 3 to 0— I/O Control A3 to A0 (IOA3 to IOA0) I/O Control C3 to C0 (IOC3 to IOC0):

IOA3 to IOA0 specify the function of TGRA. IOC3 to IOC0 specify the function of TGRC.

	Bit 3	Bit 2	Bit 1	Bit 0	
Channel	IOA3	IOA2	IOA1	IOA0	Description

		_	_				
0	0	0	0	0	TGR0A is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
	1 0 register output	1 output at compare match					
		Toggle output at compare match					
		1	0	0	_	Output disabled	
	1 Initial output is 1 output	0 output at compare match					
		output	1 output at compare match				
		1		Toggle output at compare match			
	1	0	0	0	TGR0A is	Capture input	Input capture at rising edge
				1	input	source is TIOCA0 pin	Input capture at falling edge
	capture TIOCA0 pin 1 * register Capture input source is channe 1/ count clock	Input capture at both edges					
		Input capture at TCNT1 count-up/count-down					

Channel	Bit 3 IOC3	Bit 2 IOC2	Bit 1 IOC1	Bit 0 IOC0	Description	on	
0	0	0	0	0	TGR0C is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
			1	0	-compare register*1	output	1 output at compare match
				1		Output disabled	Toggle output at compare match
		1	0	0	_		
				1	_	Initial output is 1	0 output at compare match
			1	0	_	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR0C is		Input capture at rising edge
				1	input capture	source is TIOCC0 pin	Input capture at falling edge
			1	*	register*1		Input capture at both edges
		1	*	*	_	Capture input source is channel 1/count clock	Input capture at TCNT1 count-up/count-down

Note: 1. When the BFA bit in TMDR0 is set to 1 and TGR0C is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

Channel	Bit 3 IOA3	Bit 2 IOA2	Bit 1 IOA1	Bit 0 IOA0	Description	on	
1	0	0	0	0	TGR1A is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
			1	0	–compare register	output	1 output at compare match
	1		Toggle output at compare match				
		1	0	O Output disabled			
				1	Initial output is 1	Initial output is 1	0 output at compare match
			1	0	=	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR1A is	Capture input	Input capture at rising edge
				1	input _capture	•	Input capture at falling edge
			1	*	register		Input capture at both edges
		1	*	*	_	Capture input source is TGR0A compare match/ input capture	Input capture at generation of channel 0/TGR0A compare match/input capture

Channel	Bit 3 IOA3	Bit 2 IOA2		Bit 0 IOA0	Description	on				
2	0	0	0	0	TGR2A is	Output disabled	(Initial value)			
				1	output	Initial output is 0	0 output at compare match			
			1	0	–compare register	output	1 output at compare match			
				1	_	_		_		Toggle output at compare match
		1	0	0		Output disabled				
				1	_	Initial output is 1	0 output at compare match			
			1	0	_	output	1 output at compare match			
				1	_		Toggle output at compare match			
	1	*	0	0	TGR2A is	Capture input	Input capture at rising edge			
				1	input	source is TIOCA2 pin	Input capture at falling edge			
			1	*	_capture register	πουλέ μπ	Input capture at both edges			

Channel	Bit 3 IOA3	Bit 2 IOA2	Bit 1 IOA1	Bit 0 IOA0	Description	on	
3	0	0	0	0	TGR3A is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
			1	0	–compare register	output	1 output at compare match
				1			Toggle output at compare match
		1	0	0	_	Output disabled Initial output is 1	
				1	_		0 output at compare match
			1	0	-	output	1 output at compare match
				1	_		Toggle output at compare match
	1	0	0	0	TGR3A is	Capture input	Input capture at rising edge
				1	⁻input _capture	source is TIOCA3 pin	Input capture at falling edge
			1	*	register		Input capture at both edges
		1	*	*	_	Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/count-down

Channel	Bit 3 IOC3	Bit 2 IOC2	Bit 1 IOC1	Bit 0 IOC0	Description	on								
3	0	0	0	0	TGR3C is	Output disabled	(Initial value)							
				1	output	Initial output is 0	0 output at compare match							
			1	0	-compare register*1	output	1 output at compare match							
	1 0 0 Output disabled	Toggle output at compare match												
		Output disabled												
				1 Initial output is 1	0 output at compare match									
			1	0	_	_	_	_	_			output	1 output at compare match	
				1	=		Toggle output at compare match							
	1	0	0	0	TGR3C is	Capture input	Input capture at rising edge							
				1	input —capture register*1	•	•	•	•	•	•	source is	•	Input capture at falling edge
		1	1	*		TIOCC3 pin	Input capture at both edges							
		1	*	*	=	Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/count-down							

Note: 1. When the BFA bit in TMDR3 is set to 1 and TGR3C is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

Channel	Bit 3 IOA3	Bit 2 IOA2	Bit 1 IOA1	Bit 0 IOA0	Description	on	
4	0	0	0	0	TGR4A is	Output disabled	(Initial value)
				1	output	Initial output is 0	0 output at compare match
			1	0	–compare register	output	1 output at compare match
				1			Toggle output at compare match
		1	0	0	_	Output disabled Initial output is 1 output	
				1			0 output at compare match
			1	0	_		1 output at compare match
		1		Toggle output at compare match			
	1	0	0	0	TGR4A is	Capture input	Input capture at rising edge
				1	input _capture	•	Input capture at falling edge
			1	*	register		Input capture at both edges
		1	*	*		Capture input source is TGR3A compare match/ input capture	Input capture at generation of TGR3A compare match/input capture

Channel	Bit 3 IOA3	Bit 2 IOA2		Bit 0 IOA0	Description	on						
5	0	0	0	0	TGR5A is	Output disabled	(Initial value)					
				1	output	Initial output is 0	0 output at compare match					
			1	0	–compare register	output	1 output at compare match					
				1	_ `						Toggle ou match	Toggle output at compare match
		1	0	0		Output disabled						
				1		Initial output is 1	0 output at compare match					
			1	0	_	output	1 output at compare match					
				1	=		Toggle output at compare match					
	1	*	0	0	TGR5A is	Capture input	Input capture at rising edge					
				1	input _capture	source is TIOCA5 pin	Input capture at falling edge					
			1	*	register	ΠΟΟΛΟ ΡΙΙΙ	Input capture at both edges					

10.2.4 Timer Interrupt Enable Register (TIER)

Channel 0: TIER0
Channel 3: TIER3

7 2 0 Bit : 6 5 4 3 1 TTGE **TGIED TGIEB TCIEV TGIEC TGIEA** Initial value: 0 1 0 0 0 0 0 0 R/W R/W R/W R/W R/W R/W R/W

Channel 1: TIER1
Channel 2: TIER2
Channel 4: TIER4
Channel 5: TIER5

7 Bit : 6 5 4 3 2 1 0 TTGE TCIEU **TCIEV TGIEB TGIEA** Initial value: 0 1 0 0 0 0 0 0 R/W R/W R/W R/W R/W R/W

The TIER registers are 8-bit registers that control enabling or disabling of interrupt requests for each channel. The TPU has six TIER registers, one for each channel. The TIER registers are initialized to H'40 by a reset, and in hardware standby mode.

Bit 7—A/D Conversion Start Request Enable (TTGE): Enables or disables generation of A/D conversion start requests by TGRA input capture/compare match.

Bit 7		
TTGE	Description	
0	A/D conversion start request generation disabled	(Initial value)
1	A/D conversion start request generation enabled	

Bit 6—Reserved: This bit cannot be modified and is always read as 1.

Bit 5—Underflow Interrupt Enable (TCIEU): Enables or disables interrupt requests (TCIU) by the TCFU flag when the TCFU flag in TSR is set to 1 in channels 1 and 2.

In channels 0 and 3, bit 5 is reserved. It is always read as 0 and cannot be modified.

Bit 5 TCIEU	Description	
0	Interrupt requests (TCIU) by TCFU disabled	(Initial value)
1	Interrupt requests (TCIU) by TCFU enabled	

Bit 4—Overflow Interrupt Enable (TCIEV): Enables or disables interrupt requests (TCIV) by the TCFV flag when the TCFV flag in TSR is set to 1.

Bit 4		
TCIEV	Description	
0	Interrupt requests (TCIV) by TCFV disabled	(Initial value)
1	Interrupt requests (TCIV) by TCFV enabled	

Bit 3—TGR Interrupt Enable D (TGIED): Enables or disables interrupt requests (TGID) by the TGFD bit when the TGFD bit in TSR is set to 1 in channels 0 and 3.

In channels 1, 2, 4, and 5, bit 3 is reserved. It is always read as 0 and cannot be modified.

Bit 3		
TGIED	Description	
0	Interrupt requests (TGID) by TGFD bit disabled	(Initial value)
1	Interrupt requests (TGID) by TGFD bit enabled	

Bit 2—TGR Interrupt Enable C (TGIEC): Enables or disables interrupt requests (TGIC) by the TGFC bit when the TGFC bit in TSR is set to 1 in channels 0 and 3.

In channels 1, 2, 4, and 5, bit 2 is reserved. It is always read as 0 and cannot be modified.

Bit 2		
TGIEC	Description	
0	Interrupt requests (TGIC) by TGFC bit disabled	(Initial value)
1	Interrupt requests (TGIC) by TGFC bit enabled	

Bit 1—TGR Interrupt Enable B (TGIEB): Enables or disables interrupt requests (TGIB) by the TGFB bit when the TGFB bit in TSR is set to 1.

Bit 1 TGIEB	Description	
0	Interrupt requests (TGIB) by TGFB bit disabled	(Initial value)
1	Interrupt requests (TGIB) by TGFB bit enabled	

Bit 0—TGR Interrupt Enable A (TGIEA): Enables or disables interrupt requests (TGIA) by the TGFA bit when the TGFA bit in TSR is set to 1.

Bit 0 TGIEA	Description	
0	Interrupt requests (TGIA) by TGFA bit disabled	(Initial value)
1	Interrupt requests (TGIA) by TGFA bit enabled	

10.2.5 Timer Status Register (TSR)

Channel 0: TSR0
Channel 3: TSR3

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	TCFV	TGFD	TGFC	TGFB	TGFA
Initial valu	ue:	1	1	0	0	0	0	0	0
R/W	:				R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*

Note: * Can only be written with 0 for flag clearing.

Channel 1: TSR1 Channel 2: TSR2 Channel 4: TSR4 Channel 5: TSR5

Bit	:	7	6	5	4	3	2	1	0
		TCFD	_	TCFU	TCFV			TGFB	TGFA
Initial value	e:	1	1	0	0	0	0	0	0
R/W	:	R	_	R/(W)*	R/(W)*	_	_	R/(W)*	R/(W)*

Note: * Can only be written with 0 for flag clearing.

The TSR registers are 8-bit registers that indicate the status of each channel. The TPU has six TSR registers, one for each channel. The TSR registers are initialized to H'C0 by a reset, and in hardware standby mode.

Bit 7—Count Direction Flag (TCFD): Status flag that shows the direction in which TCNT counts in channels 1, 2, 4, and 5.

In channels 0 and 3, bit 7 is reserved. It is always read as 1 and cannot be modified.

Bit 7 TCFD	Description	
0	TCNT counts down	
1	TCNT counts up	(Initial value)

Bit 6—Reserved: This bit cannot be modified and is always read as 1.

Bit 5—Underflow Flag (TCFU): Status flag that indicates that TCNT underflow has occurred when channels 1, 2, 4, and 5 are set to phase counting mode.

In channels 0 and 3, bit 5 is reserved. It is always read as 0 and cannot be modified.

Bit 5 TCFU	Description	
0	[Clearing condition] When 0 is written to TCFU after reading TCFU = 1	(Initial value)
1	[Setting condition] When the TCNT value underflows (changes from H'0000 to H'FFFF)	

Bit 4—Overflow Flag (TCFV): Status flag that indicates that TCNT overflow has occurred.

Bit 4 TCFV	Description	
0	[Clearing condition]	(Initial value)
	When 0 is written to TCFV after reading TCFV = 1	
1	[Setting condition]	
	When the TCNT value overflows (changes from H'FFFF to H'0000)	

Bit 3—Input Capture/Output Compare Flag D (TGFD): Status flag that indicates the occurrence of TGRD input capture or compare match in channels 0 and 3.

In channels 1, 2, 4, and 5, bit 3 is reserved. It is always read as 0 and cannot be modified.

Bit 3 TGFD	Description
0	[Clearing conditions] (Initial value)
	 When DTC is activated by TGID interrupt while DISEL bit of MRB in DTC is 0
	 When 0 is written to TGFD after reading TGFD = 1
1	[Setting conditions]
	 When TCNT = TGRD while TGRD is functioning as output compare register
	When TCNT value is transferred to TGRD by input capture signal while TGRD is
	functioning as input capture register

Bit 2—Input Capture/Output Compare Flag C (TGFC): Status flag that indicates the occurrence of TGRC input capture or compare match in channels 0 and 3.

In channels 1, 2, 4, and 5, bit 2 is reserved. It is always read as 0 and cannot be modified.

Bit 2 TGFC	Description
0	[Clearing conditions] (Initial value)
	 When DTC is activated by TGIC interrupt while DISEL bit of MRB in DTC is 0
	 When 0 is written to TGFC after reading TGFC = 1
1	[Setting conditions]
	 When TCNT = TGRC while TGRC is functioning as output compare register
	 When TCNT value is transferred to TGRC by input capture signal while TGRC is
	functioning as input capture register

Bit 1—Input Capture/Output Compare Flag B (TGFB): Status flag that indicates the occurrence of TGRB input capture or compare match.

Bit 1 TGFB	Description
0	[Clearing conditions] (Initial value)
	 When DTC is activated by TGIB interrupt while DISEL bit of MRB in DTC is 0
	 When 0 is written to TGFB after reading TGFB = 1
1	[Setting conditions]
	 When TCNT = TGRB while TGRB is functioning as output compare register
	 When TCNT value is transferred to TGRB by input capture signal while TGRB is functioning as input capture register

Bit 0—Input Capture/Output Compare Flag A (TGFA): Status flag that indicates the occurrence of TGRA input capture or compare match.

Bit 0 TGFA	Description					
0	[Clearing conditions] (Initial value)					
	 When DTC is activated by TGIA interrupt while DISEL bit of MRB in DTC is 0 					
	 When DMAC is activated by TGIA interrupt while DTA bit of DMABCR in DMAC is 					
	 When 0 is written to TGFA after reading TGFA = 1 					
1	[Setting conditions]					
	 When TCNT = TGRA while TGRA is functioning as output compare register 					
	 When TCNT value is transferred to TGRA by input capture signal while TGRA is functioning as input capture register 					

10.2.6 Timer Counter (TCNT)

Channel 0: TCNT0 (up-counter)

Channel 1: TCNT1 (up/down-counter*)

Channel 2: TCNT2 (up/down-counter*)

Channel 3: TCNT3 (up-counter)

Channel 4: TCNT4 (up/down-counter*)
Channel 5: TCNT5 (up/down-counter*)

Bit Initial value: O O O R/W

Note: *These counters can be used as up/down-counters only in phase counting mode or when counting overflow/underflow on another channel. In other cases they function as upcounters.

The TCNT registers are 16-bit counters. The TPU has six TCNT counters, one for each channel.

The TCNT counters are initialized to H'0000 by a reset, and in hardware standby mode.

The TCNT counters cannot be accessed in 8-bit units; they must always be accessed as a 16-bit unit.

10.2.7 Timer General Register (TGR)

Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
Initial value:	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	

 $\mathsf{R/W} \qquad : \ \mathsf{R/W}$

The TGR registers are 16-bit registers with a dual function as output compare and input capture registers. The TPU has 16 TGR registers, four each for channels 0 and 3 and two each for channels 1, 2, 4, and 5. TGRC and TGRD for channels 0 and 3 can also be designated for operation as buffer registers*. The TGR registers are initialized to H'FFFF by a reset, and in hardware standby mode.

The TGR registers cannot be accessed in 8-bit units; they must always be accessed as a 16-bit unit.

Note: * TGR buffer register combinations are TGRA—TGRC and TGRB—TGRD.

10.2.8 Timer Start Register (TSTR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	CST5	CST4	CST3	CST2	CST1	CST0
Initial valu	ıe:	0	0	0	0	0	0	0	0
R/W	:	_	_	R/W	R/W	R/W	R/W	R/W	R/W

TSTR is an 8-bit readable/writable register that selects operation/stoppage for channels 0 to 5. TSTR is initialized to H'00 by a reset, and in hardware standby mode. When setting the operating mode in TMDR or setting the count clock in TCR, first stop the TCNT counter.

Bits 7 and 6—Reserved: Should always be written with 0.

Bits 5 to 0—Counter Start 5 to 0 (CST5 to CST0): These bits select operation or stoppage for TCNT.

Bit n CSTn	Description	
0	TCNTn count operation is stopped	(Initial value)
1	TCNTn performs count operation	
		n = 5 to 0

Note: If 0 is written to the CST bit during operation with the TIOC pin designated for output, the counter stops but the TIOC pin output compare output level is retained. If TIOR is written to when the CST bit is cleared to 0, the pin output level will be changed to the set initial output value.

10.2.9 Timer Synchro Register (TSYR)

Bit :	7	6	5	4	3	2	1	0
			SYNC5	SYNC4	SYNC3	SYNC2	SYNC1	SYNC0
Initial value:	0	0	0	0	0	0	0	0
R/W :		_	R/W	R/W	R/W	R/W	R/W	R/W

TSYR is an 8-bit readable/writable register that selects independent operation or synchronous operation for the channel 0 to 4 TCNT counters. A channel performs synchronous operation when the corresponding bit in TSYR is set to 1.

TSYR is initialized to H'00 by a reset, and in hardware standby mode.

Bits 7 and 6—Reserved: Should always be written with 0.

Bits 5 to 0—Timer Synchro 5 to 0 (SYNC5 to SYNC0): These bits select whether operation is independent of or synchronized with other channels.

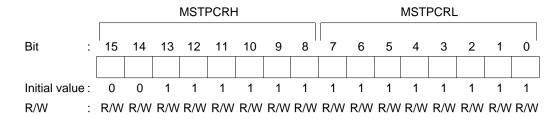
When synchronous operation is selected, synchronous presetting of multiple channels*1, and synchronous clearing through counter clearing on another channel*2 are possible.

Bit n SYNCn	Description	
0	TCNTn operates independently (TCNT presetting/clearing is unrelated to other channels)	(Initial value)
1	TCNTn performs synchronous operation	
	TCNT synchronous presetting/synchronous clearing is possible	
•		n = 5 to 0

Notes: 1. To set synchronous operation, the SYNC bits for at least two channels must be set to 1.

2. To set synchronous clearing, in addition to the SYNC bit , the TCNT clearing source must also be set by means of bits CCLR2 to CCLR0 in TCR.

10.2.10 Module Stop Control Register (MSTPCR)



MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP13 bit in MSTPCR is set to 1, TPU operation stops at the end of the bus cycle and a transition is made to module stop mode. Registers cannot be read or written to in module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 13—Module Stop (MSTP13): Specifies the TPU module stop mode.

Bit 13 MSTP13 Description

0	TPU module stop mode cleared	
1	TPU module stop mode set	(Initial value)

10.3 Interface to Bus Master

10.3.1 16-Bit Registers

TCNT and TGR are 16-bit registers. As the data bus to the bus master is 16 bits wide, these registers can be read and written to in 16-bit units.

These registers cannot be read or written to in 8-bit units; 16-bit access must always be used.

An example of 16-bit register access operation is shown in figure 10-2.

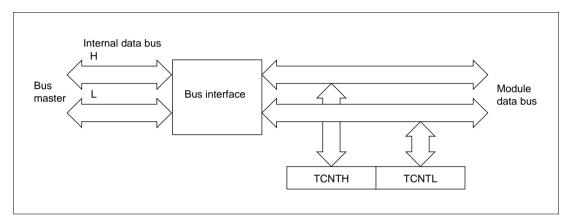


Figure 10-2 16-Bit Register Access Operation [Bus Master ↔ TCNT (16 Bits)]

10.3.2 8-Bit Registers

Registers other than TCNT and TGR are 8-bit. As the data bus to the CPU is 16 bits wide, these registers can be read and written to in 16-bit units. They can also be read and written to in 8-bit units.

Examples of 8-bit register access operation are shown in figures 10-3, 10-4, and 10-5.

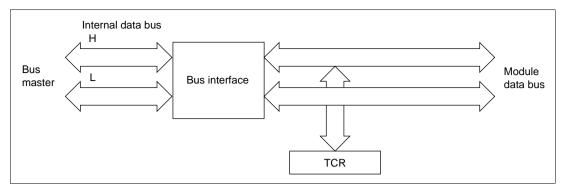


Figure 10-3 8-Bit Register Access Operation [Bus Master ↔ TCR (Upper 8 Bits)]

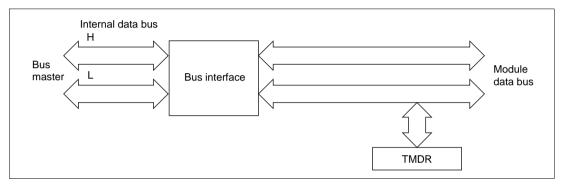
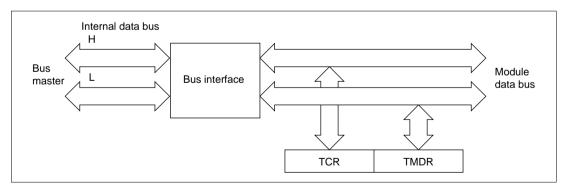


Figure 10-4 8-Bit Register Access Operation [Bus Master ↔ TMDR (Lower 8 Bits)]



 $Figure~10\text{--}5~8\text{--Bit Register Access Operation [Bus Master} \leftrightarrow TCR~and~TMDR~(16~Bits)]$

10.4 Operation

10.4.1 Overview

Operation in each mode is outlined below.

Normal Operation: Each channel has a TCNT and TGR register. TCNT performs up-counting, and is also capable of free-running operation, synchronous counting, and external event counting.

Each TGR can be used as an input capture register or output compare register.

Synchronous Operation: When synchronous operation is designated for a channel, TCNT for that channel performs synchronous presetting. That is, when TCNT for a channel designated for synchronous operation is rewritten, the TCNT counters for the other channels are also rewritten at the same time. Synchronous clearing of the TCNT counters is also possible by setting the timer synchronization bits in TSYR for channels designated for synchronous operation.

Buffer Operation

- When TGR is an output compare register
 When a compare match occurs, the value in the buffer register for the relevant channel is transferred to TGR.
- When TGR is an input capture register
 When input capture occurs, the value in TCNT is transfer to TGR and the value previously held in TGR is transferred to the buffer register.

Cascaded Operation: The channel 1 counter (TCNT1), channel 2 counter (TCNT2), channel 4 counter (TCNT4), and channel 5 counter (TCNT5) can be connected together to operate as a 32-bit counter.

PWM Mode: In this mode, a PWM waveform is output. The output level can be set by means of TIOR. A PWM waveform with a duty of between 0% and 100% can be output, according to the setting of each TGR register.

Phase Counting Mode: In this mode, TCNT is incremented or decremented by detecting the phases of two clocks input from the external clock input pins in channels 1, 2, 4, and 5. When phase counting mode is set, the corresponding TCLK pin functions as the clock pin, and TCNT performs up- or down-counting.

This can be used for two-phase encoder pulse input.

10.4.2 Basic Functions

Counter Operation: When one of bits CST0 to CST5 is set to 1 in TSTR, the TCNT counter for the corresponding channel starts counting. TCNT can operate as a free-running counter, periodic counter, and so on.

• Example of count operation setting procedure

Figure 10-6 shows an example of the count operation setting procedure.

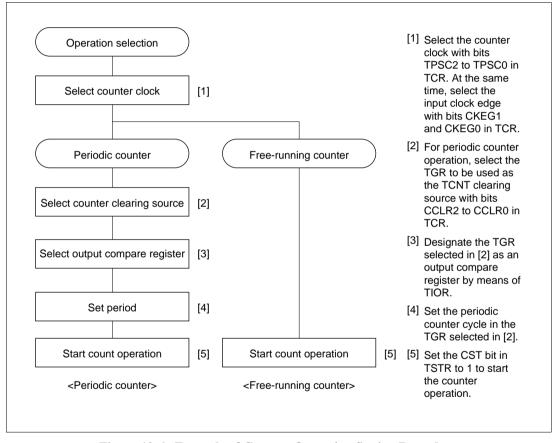


Figure 10-6 Example of Counter Operation Setting Procedure

• Free-running count operation and periodic count operation
Immediately after a reset, the TPU's TCNT counters are all designated as free-running
counters. When the relevant bit in TSTR is set to 1 the corresponding TCNT counter starts upcount operation as a free-running counter. When TCNT overflows (from H'FFFF to H'0000),
the TCFV bit in TSR is set to 1. If the value of the corresponding TCIEV bit in TIER is 1 at
this point, the TPU requests an interrupt. After overflow, TCNT starts counting up again from
H'0000.

Figure 10-7 illustrates free-running counter operation.

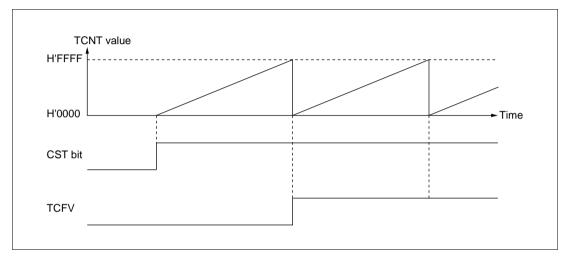


Figure 10-7 Free-Running Counter Operation

When compare match is selected as the TCNT clearing source, the TCNT counter for the relevant channel performs periodic count operation. The TGR register for setting the period is designated as an output compare register, and counter clearing by compare match is selected by means of bits CCLR2 to CCLR0 in TCR. After the settings have been made, TCNT starts up-count operation as periodic counter when the corresponding bit in TSTR is set to 1. When the count value matches the value in TGR, the TGF bit in TSR is set to 1 and TCNT is cleared to H'0000.

If the value of the corresponding TGIE bit in TIER is 1 at this point, the TPU requests an interrupt. After a compare match, TCNT starts counting up again from H'0000.

Figure 10-8 illustrates periodic counter operation.

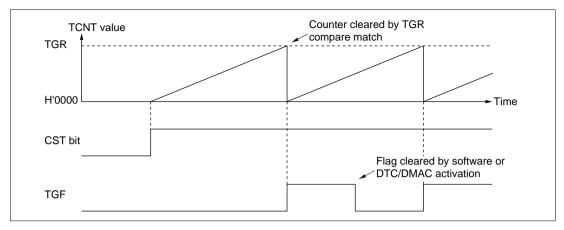


Figure 10-8 Periodic Counter Operation

Waveform Output by Compare Match: The TPU can perform 0, 1, or toggle output from the corresponding output pin using compare match.

• Example of setting procedure for waveform output by compare match
Figure 10-9 shows an example of the setting procedure for waveform output by compare match

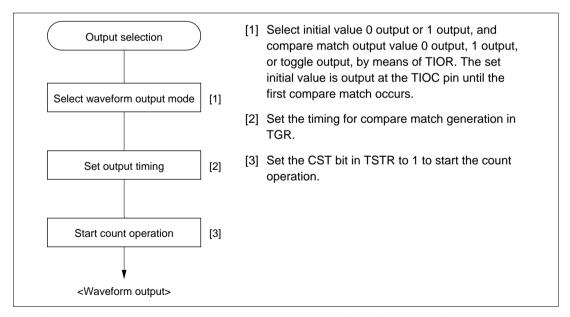


Figure 10-9 Example Of Setting Procedure For Waveform Output By Compare Match

• Examples of waveform output operation Figure 10-10 shows an example of 0 output/1 output.

In this example TCNT has been designated as a free-running counter, and settings have been made so that 1 is output by compare match A, and 0 is output by compare match B. When the set level and the pin level coincide, the pin level does not change.

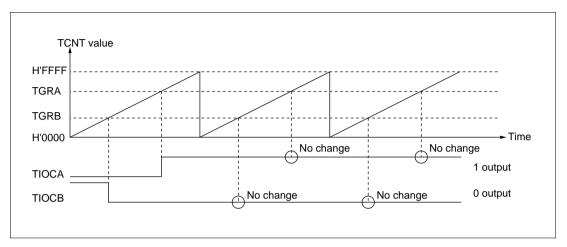


Figure 10-10 Example of 0 Output/1 Output Operation

Figure 10-11 shows an example of toggle output.

In this example TCNT has been designated as a periodic counter (with counter clearing performed by compare match B), and settings have been made so that output is toggled by both compare match A and compare match B.

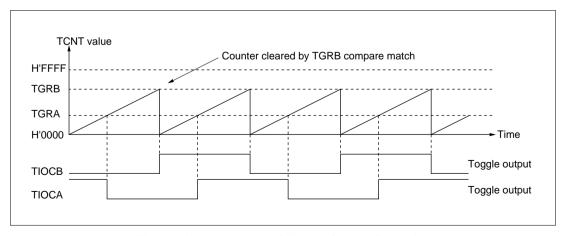


Figure 10-11 Example of Toggle Output Operation

Input Capture Function: The TCNT value can be transferred to TGR on detection of the TIOC pin input edge.

Rising edge, falling edge, or both edges can be selected as the detected edge. For channels 0, 1, 3, and 4, it is also possible to specify another channel's counter input clock or compare match signal as the input capture source.

Note: When another channel's counter input clock is used as the input capture input for channels 0 and 3, $\emptyset/1$ should not be selected as the counter input clock used for input capture input. Input capture will not be generated if $\emptyset/1$ is selected.

Example of input capture operation setting procedure
 Figure 10-12 shows an example of the input capture operation setting procedure.

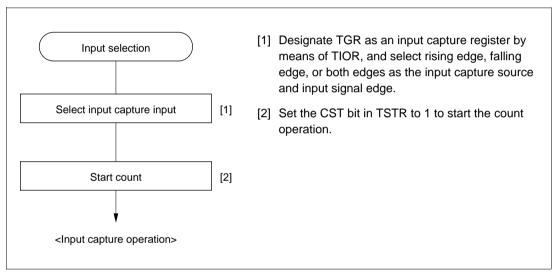


Figure 10-12 Example of Input Capture Operation Setting Procedure

• Example of input capture operation
Figure 10-13 shows an example of input capture operation.

In this example both rising and falling edges have been selected as the TIOCA pin input capture input edge, falling edge has been selected as the TIOCB pin input capture input edge, and counter clearing by TGRB input capture has been designated for TCNT.

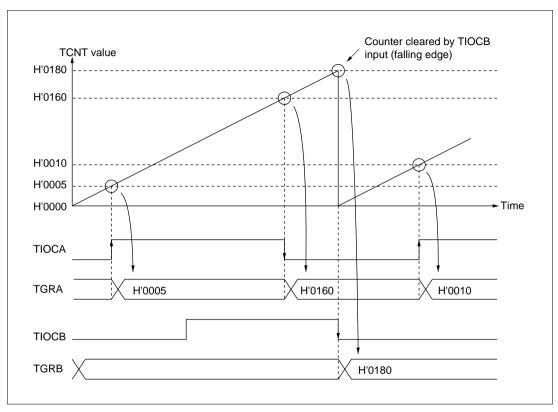


Figure 10-13 Example of Input Capture Operation

10.4.3 Synchronous Operation

In synchronous operation, the values in a number of TCNT counters can be rewritten simultaneously (synchronous presetting). Also, a number of TCNT counters can be cleared simultaneously by making the appropriate setting in TCR (synchronous clearing).

Synchronous operation enables TGR to be incremented with respect to a single time base.

Channels 0 to 5 can all be designated for synchronous operation.

Example of Synchronous Operation Setting Procedure: Figure 10-14 shows an example of the synchronous operation setting procedure.

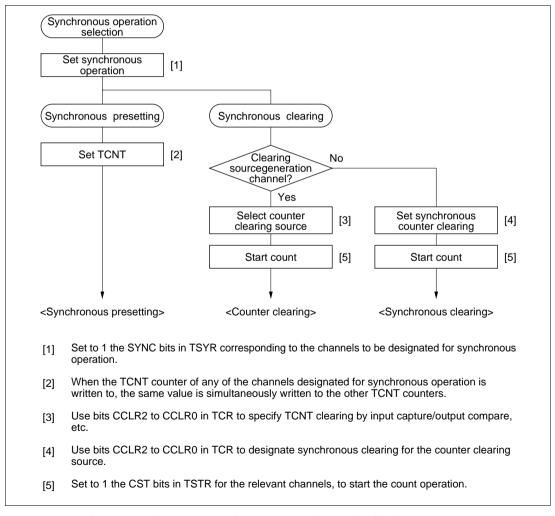


Figure 10-14 Example of Synchronous Operation Setting Procedure

Example of Synchronous Operation: Figure 10-15 shows an example of synchronous operation.

In this example, synchronous operation and PWM mode 1 have been designated for channels 0 to 2, TGR0B compare match has been set as the channel 0 counter clearing source, and synchronous clearing has been set for the channel 1 and 2 counter clearing source.

Three-phase PWM waveforms are output from pins TIOC0A, TIOC1A, and TIOC2A. At this time, synchronous presetting, and synchronous clearing by TGR0B compare match, is performed for channel 0 to 2 TCNT counters, and the data set in TGR0B is used as the PWM cycle.

For details of PWM modes, see section 10.4.6, PWM Modes.

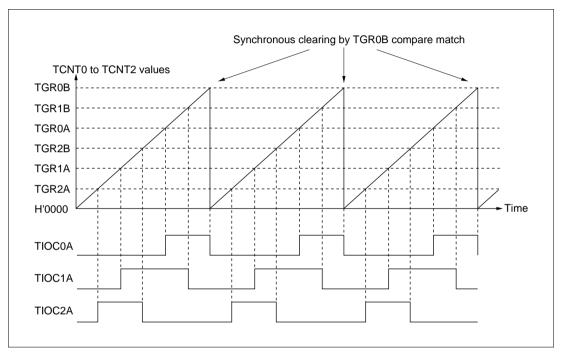


Figure 10-15 Example of Synchronous Operation

10.4.4 Buffer Operation

Buffer operation, provided for channels 0 and 3, enables TGRC and TGRD to be used as buffer registers.

Buffer operation differs depending on whether TGR has been designated as an input capture register or as a compare match register.

Table 10-5 shows the register combinations used in buffer operation.

Table 10-5 Register Combinations in Buffer Operation

Channel	Timer General Register	Buffer Register
0	TGR0A	TGR0C
	TGR0B	TGR0D
3	TGR3A	TGR3C
	TGR3B	TGR3D

• When TGR is an output compare register

When a compare match occurs, the value in the buffer register for the corresponding channel is transferred to the timer general register.

This operation is illustrated in figure 10-16.

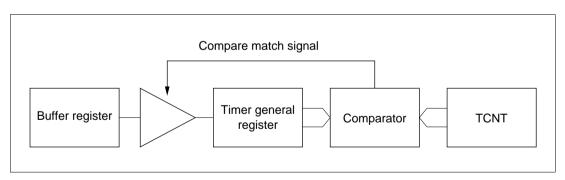


Figure 10-16 Compare Match Buffer Operation

When TGR is an input capture register
 When input capture occurs, the value in TCNT is transferred to TGR and the value previously held in the timer general register is transferred to the buffer register.

This operation is illustrated in figure 10-17.

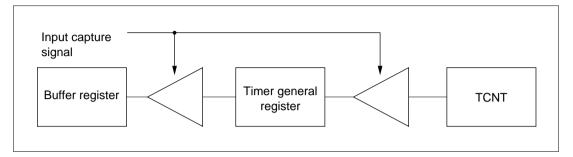


Figure 10-17 Input Capture Buffer Operation

Example of Buffer Operation Setting Procedure: Figure 10-18 shows an example of the buffer operation setting procedure.

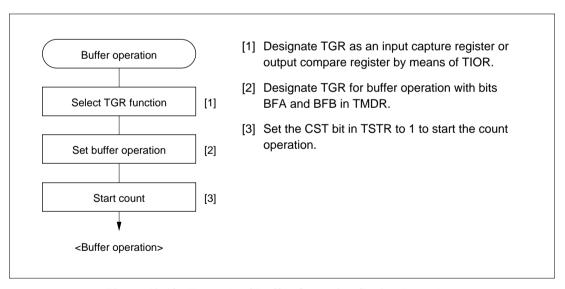


Figure 10-18 Example of Buffer Operation Setting Procedure

Examples of Buffer Operation

• When TGR is an output compare register

Figure 10-19 shows an operation example in which PWM mode 1 has been designated for channel 0, and buffer operation has been designated for TGRA and TGRC. The settings used in this example are TCNT clearing by compare match B, 1 output at compare match A, and 0 output at compare match B.

As buffer operation has been set, when compare match A occurs the output changes and the value in buffer register TGRC is simultaneously transferred to timer general register TGRA. This operation is repeated each time compare match A occurs.

For details of PWM modes, see section 10.4.6, PWM Modes.

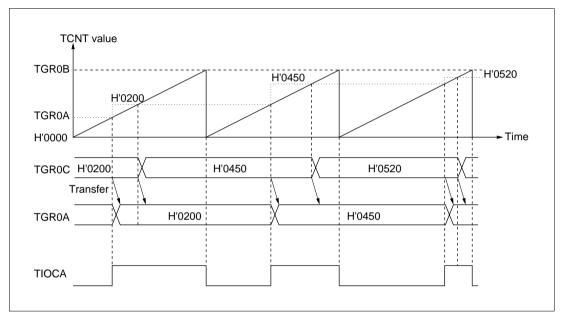


Figure 10-19 Example of Buffer Operation (1)

• When TGR is an input capture register

Figure 10-20 shows an operation example in which TGRA has been designated as an input capture register, and buffer operation has been designated for TGRA and TGRC.

Counter clearing by TGRA input capture has been set for TCNT, and both rising and falling edges have been selected as the TIOCA pin input capture input edge.

As buffer operation has been set, when the TCNT value is stored in TGRA upon occurrence of input capture A, the value previously stored in TGRA is simultaneously transferred to TGRC.

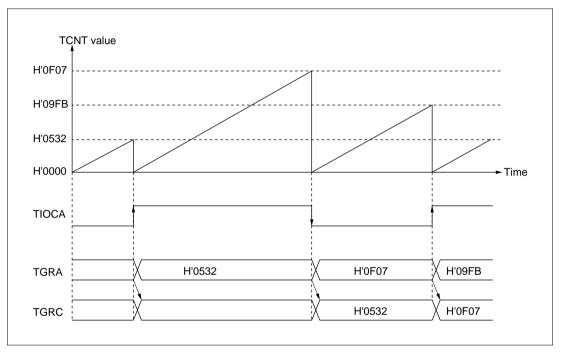


Figure 10-20 Example of Buffer Operation (2)

10.4.5 Cascaded Operation

In cascaded operation, two 16-bit counters for different channels are used together as a 32-bit counter.

This function works by counting the channel 1 (channel 4) counter clock upon overflow/underflow of TCNT2 (TCNT5) as set in bits TPSC2 to TPSC0 in TCR.

Underflow occurs only when the lower 16-bit TCNT is in phase-counting mode.

Table 10-6 shows the register combinations used in cascaded operation.

Note: When phase counting mode is set for channel 1 or 4, the counter clock setting is invalid and the counter operates independently in phase counting mode.

Table 10-6 Cascaded Combinations

Combination	Upper 16 Bits	Lower 16 Bits
Channels 1 and 2	TCNT1	TCNT2
Channels 4 and 5	TCNT4	TCNT5

Example of Cascaded Operation Setting Procedure: Figure 10-21 shows an example of the setting procedure for cascaded operation.

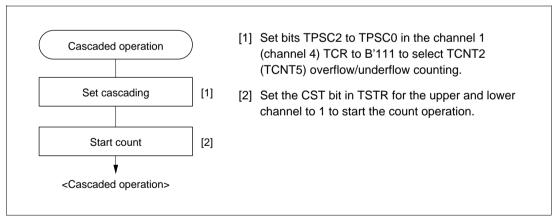


Figure 10-21 Cascaded Operation Setting Procedure

Examples of Cascaded Operation: Figure 10-22 illustrates the operation when counting upon TCNT2 overflow/underflow has been set for TCNT1, TGR1A and TGR2A have been designated as input capture registers, and TIOC pin rising edge has been selected.

When a rising edge is input to the TIOCA1 and TIOCA2 pins simultaneously, the upper 16 bits of the 32-bit data are transferred to TGR1A, and the lower 16 bits to TGR2A.

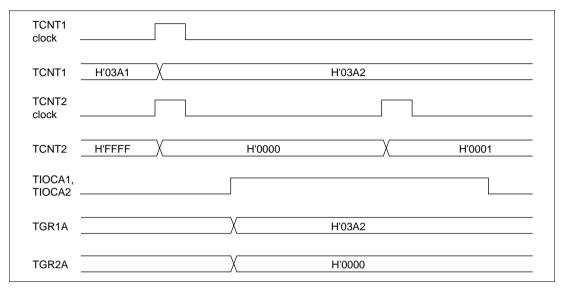


Figure 10-22 Example of Cascaded Operation (1)

Figure 10-23 illustrates the operation when counting upon TCNT2 overflow/underflow has been set for TCNT1, and phase counting mode has been designated for channel 2.

TCNT1 is incremented by TCNT2 overflow and decremented by TCNT2 underflow.

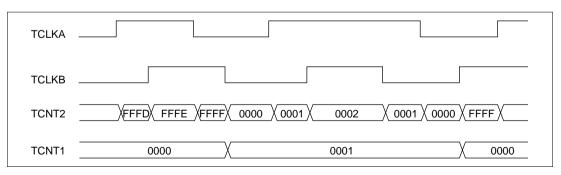


Figure 10-23 Example of Cascaded Operation (2)

10.4.6 PWM Modes

In PWM mode, PWM waveforms are output from the output pins. 0, 1, or toggle output can be selected as the output level in response to compare match of each TGR.

Designating TGR compare match as the counter clearing source enables the period to be set in that register. All channels can be designated for PWM mode independently. Synchronous operation is also possible.

There are two PWM modes, as described below.

PWM mode 1

PWM output is generated from the TIOCA and TIOCC pins by pairing TGRA with TGRB and TGRC with TGRD. The output specified by bits IOA3 to IOA0 and IOC3 to IOC0 in TIOR is output from the TIOCA and TIOCC pins at compare matches A and C, and the output specified by bits IOB3 to IOB0 and IOD3 to IOD0 in TIOR is output at compare matches B and D. The initial output value is the value set in TGRA or TGRC. If the set values of paired TGRs are identical, the output value does not change when a compare match occurs. In PWM mode 1, a maximum 8-phase PWM output is possible.

PWM mode 2

PWM output is generated using one TGR as the cycle register and the others as duty registers. The output specified in TIOR is performed by means of compare matches. Upon counter clearing by a synchronization register compare match, the output value of each pin is the initial value set in TIOR. If the set values of the cycle and duty registers are identical, the output value does not change when a compare match occurs.

In PWM mode 2, a maximum 15-phase PWM output is possible by combined use with synchronous operation.

The correspondence between PWM output pins and registers is shown in table 10-7.

Table 10-7 PWM Output Registers and Output Pins

TGR5B

	Registers	Output Pins	
Channel		PWM Mode 1	PWM Mode 2
0	TGR0A	TIOCA0	TIOCA0
	TGR0B		TIOCB0
	TGR0C	TIOCC0	TIOCC0
	TGR0D		TIOCD0
1	TGR1A	TIOCA1	TIOCA1
	TGR1B		TIOCB1
2	TGR2A	TIOCA2	TIOCA2
	TGR2B		TIOCB2
3	TGR3A	TIOCA3	TIOCA3
	TGR3B		TIOCB3
	TGR3C	TIOCC3	TIOCC3
	TGR3D		TIOCD3
4	TGR4A	TIOCA4	TIOCA4
	TGR4B		TIOCB4
5	TGR5A	TIOCA5	TIOCA5
			-

Note: In PWM mode 2, PWM output is not possible for the TGR register in which the period is set.

TIOCB5

Example of PWM Mode Setting Procedure: Figure 10-24 shows an example of the PWM mode setting procedure.

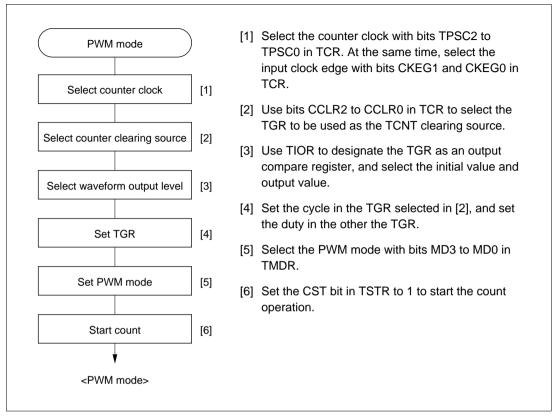


Figure 10-24 Example of PWM Mode Setting Procedure

Examples of PWM Mode Operation: Figure 10-25 shows an example of PWM mode 1 operation.

In this example, TGRA compare match is set as the TCNT clearing source, 0 is set for the TGRA initial output value and output value, and 1 is set as the TGRB output value.

In this case, the value set in TGRA is used as the period, and the values set in TGRB registers as the duty.

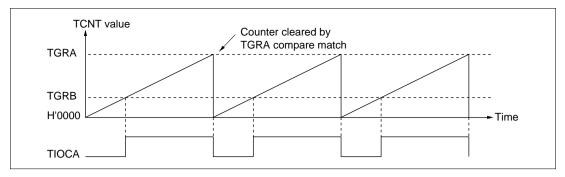


Figure 10-25 Example of PWM Mode Operation (1)

Figure 10-26 shows an example of PWM mode 2 operation.

In this example, synchronous operation is designated for channels 0 and 1, TGR1B compare match is set as the TCNT clearing source, and 0 is set for the initial output value and 1 for the output value of the other TGR registers (TGR0A to TGR0D, TGR1A), to output a 5-phase PWM waveform.

In this case, the value set in TGR1B is used as the cycle, and the values set in the other TGRs as the duty.

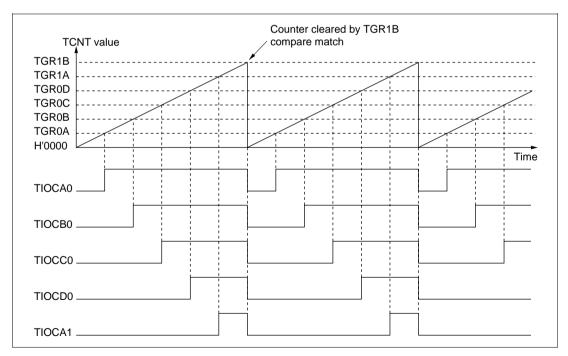


Figure 10-26 Example of PWM Mode Operation (2)

Figure 10-27 shows examples of PWM waveform output with 0% duty and 100% duty in PWM mode.

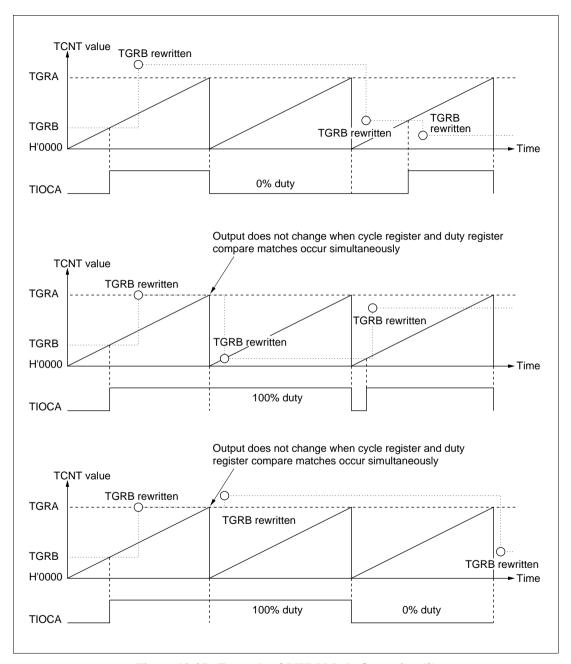


Figure 10-27 Example of PWM Mode Operation (3)

10.4.7 Phase Counting Mode

In phase counting mode, the phase difference between two external clock inputs is detected and TCNT is incremented/decremented accordingly. This mode can be set for channels 1, 2, 4, and 5.

When phase counting mode is set, an external clock is selected as the counter input clock and TCNT operates as an up/down-counter regardless of the setting of bits TPSC2 to TPSC0 and bits CKEG1 and CKEG0 in TCR. However, the functions of bits CCLR1 and CCLR0 in TCR, and of TIOR, TIER, and TGR are valid, and input capture/compare match and interrupt functions can be used.

When overflow occurs while TCNT is counting up, the TCFV flag in TSR is set; when underflow occurs while TCNT is counting down, the TCFU flag is set.

The TCFD bit in TSR is the count direction flag. Reading the TCFD flag provides an indication of whether TCNT is counting up or down.

Table 10-8 shows the correspondence between external clock pins and channels.

Table 10-8 Phase Counting Mode Clock Input Pins

	External Clock Pins	
Channels	A-Phase	B-Phase
When channel 1 or 5 is set to phase counting mode	TCLKA	TCLKB
When channel 2 or 4 is set to phase counting mode	TCLKC	TCLKD

Example of Phase Counting Mode Setting Procedure: Figure 10-28 shows an example of the phase counting mode setting procedure.

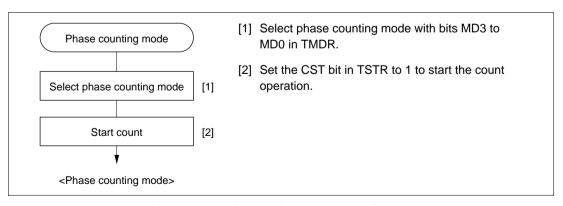


Figure 10-28 Example of Phase Counting Mode Setting Procedure

Examples of Phase Counting Mode Operation: In phase counting mode, TCNT counts up or down according to the phase difference between two external clocks. There are four modes, according to the count conditions.

Phase counting mode 1
 Figure 10-29 shows an example of phase counting mode 1 operation, and table 10-9
 summarizes the TCNT up/down-count conditions.

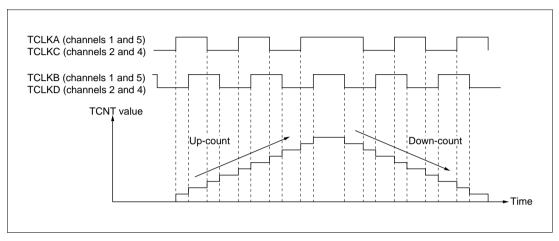


Figure 10-29 Example of Phase Counting Mode 1 Operation

Table 10-9 Up/Down-Count Conditions in Phase Counting Mode 1

TCLKA (Channels 1 and 5) TCLKC (Channels 2 and 4)	TCLKB (Channels 1 and 5) TCLKD (Channels 2 and 4)	Operation
High level		Up-count
Low level	7_	
<u></u>	Low level	
7_	High level	
High level	7_	Down-count
Low level		
<u>_</u>	High level	
7_	Low level	

Legend

 Phase counting mode 2
Figure 10-30 shows an example of phase counting mode 2 operation, and table 10-10 summarizes the TCNT up/down-count conditions.

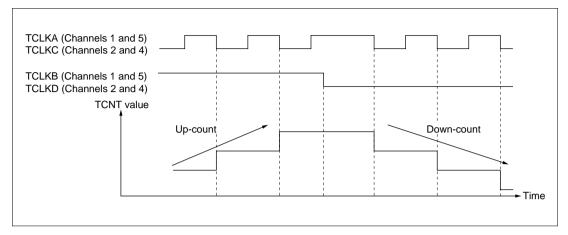


Figure 10-30 Example of Phase Counting Mode 2 Operation

Table 10-10 Up/Down-Count Conditions in Phase Counting Mode 2

TCLKA (Channels 1 and 5) TCLKC (Channels 2 and 4)	TCLKB (Channels 1 and 5) TCLKD (Channels 2 and 4)	Operation
High level	<u> </u>	Don't care
Low level	7_	Don't care
<u>_</u>	Low level	Don't care
Ŧ.	High level	Up-count
High level	7_	Don't care
Low level	£	Don't care
<u></u>	High level	Don't care
Z	Low level	Down-count

Legend

• Phase counting mode 3

Figure 10-31 shows an example of phase counting mode 3 operation, and table 10-11 summarizes the TCNT up/down-count conditions.

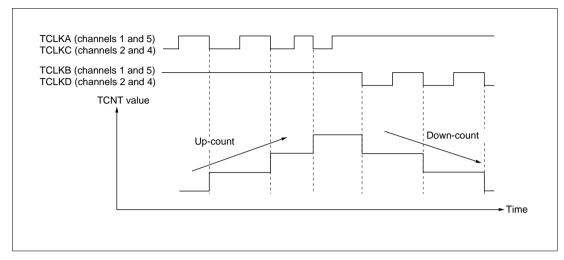


Figure 10-31 Example of Phase Counting Mode 3 Operation

Table 10-11 Up/Down-Count Conditions in Phase Counting Mode 3

TCLKA (Channels 1 and 5) TCLKC (Channels 2 and 4)	TCLKB (Channels 1 and 5) TCLKD (Channels 2 and 4)	Operation
High level	<u> </u>	Don't care
Low level	7_	Don't care
<u></u>	Low level	Don't care
7_	High level	Up-count
High level	7_	Down-count
Low level		Don't care
<u>_</u>	High level	Don't care
7_	Low level	Don't care

Legend

 Phase counting mode 4
 Figure 10-32 shows an example of phase counting mode 4 operation, and table 10-12 summarizes the TCNT up/down-count conditions.

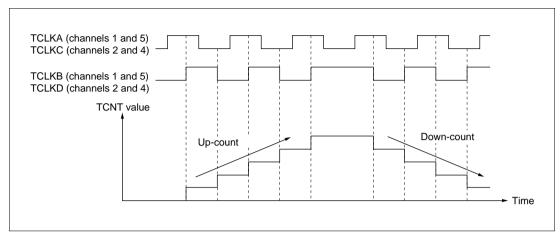


Figure 10-32 Example of Phase Counting Mode 4 Operation

Table 10-12 Up/Down-Count Conditions in Phase Counting Mode 4

TCLKA (Channels 1 and 5) TCLKC (Channels 2 and 4)	TCLKB (Channels 1 and 5) TCLKD (Channels 2 and 4)	Operation
High level		Up-count
Low level	7_	
<u></u>	Low level	Don't care
7_	High level	
High level	7_	Down-count
Low level	<u>_</u>	
<u>_</u>	High level	Don't care
7_	Low level	

Legend

☐ : Rising edge ☐ : Falling edge

Phase Counting Mode Application Example: Figure 10-33 shows an example in which phase counting mode is designated for channel 1, and channel 1 is coupled with channel 0 to input servo motor 2-phase encoder pulses in order to detect the position or speed.

Channel 1 is set to phase counting mode 1, and the encoder pulse A-phase and B-phase are input to TCLKA and TCLKB.

Channel 0 operates with TCNT counter clearing by TGR0C compare match; TGR0A and TGR0C are used for the compare match function, and are set with the speed control period and position control period. TGR0B is used for input capture, with TGR0B and TGR0D operating in buffer mode. The channel 1 counter input clock is designated as the TGR0B input capture source, and detection of the pulse width of 2-phase encoder 4-multiplication pulses is performed.

TGR1A and TGR1B for channel 1 are designated for input capture, channel 0 TGR0A and TGR0C compare matches are selected as the input capture source, and store the up/down-counter values for the control periods.

This procedure enables accurate position/speed detection to be achieved.

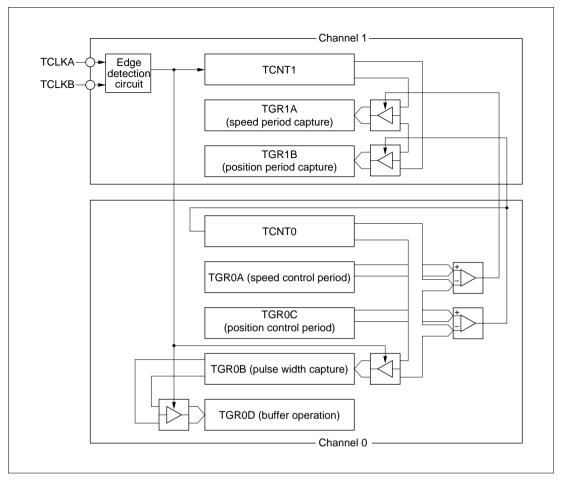


Figure 10-33 Phase Counting Mode Application Example

10.5 Interrupts

10.5.1 Interrupt Sources and Priorities

There are three kinds of TPU interrupt source: TGR input capture/compare match, TCNT overflow, and TCNT underflow. Each interrupt source has its own status flag and enable/disabled bit, allowing generation of interrupt request signals to be enabled or disabled individually.

When an interrupt request is generated, the corresponding status flag in TSR is set to 1. If the corresponding enable/disable bit in TIER is set to 1 at this time, an interrupt is requested. The interrupt request is cleared by clearing the status flag to 0.

Relative channel priorities can be changed by the interrupt controller, but the priority order within a channel is fixed. For details, see section 5, Interrupt Controller.

Table 10-13 lists the TPU interrupt sources.

Table 10-13 TPU Interrupts

Channel	Interrupt Source	Description	DMAC Activation	DTC Activation	Priority
0	TGI0A	TGR0A input capture/compare match	Possible	Possible	High
	TGI0B	TGR0B input capture/compare match	Not possible	Possible	_ \
	TGI0C	TGR0C input capture/compare match	Not possible	Possible	_
	TGI0D	TGR0D input capture/compare match	Not possible	Possible	
	TCI0V	TCNT0 overflow	Not possible	Not possible	
1	TGI1A	TGR1A input capture/compare match	Possible	Possible	
	TGI1B	TGR1B input capture/compare match	Not possible	Possible	
	TCI1V	TCNT1 overflow	Not possible	Not possible	
	TCI1U	TCNT1 underflow	Not possible	Not possible	_
2	TGI2A	TGR2A input capture/compare match	Possible	Possible	
	TGI2B	TGR2B input capture/compare match	Not possible	Possible	_
	TCI2V	TCNT2 overflow	Not possible	Not possible	_
	TCI2U	TCNT2 underflow	Not possible	Not possible	_
3	TGI3A	TGR3A input capture/compare match	Possible	Possible	
	TGI3B	TGR3B input capture/compare match	Not possible	Possible	_
	TGI3C	TGR3C input capture/compare match	Not possible	Possible	
	TGI3D	TGR3D input capture/compare match	Not possible	Possible	
	TCI3V	TCNT3 overflow	Not possible	Not possible	_
4	TGI4A	TGR4A input capture/compare match	Possible	Possible	
	TGI4B	TGR4B input capture/compare match	Not possible	Possible	
	TCI4V	TCNT4 overflow	Not possible	Not possible	
	TCI4U	TCNT4 underflow	Not possible	Not possible	
5	TGI5A	TGR5A input capture/compare match	Possible	Possible	_
	TGI5B	TGR5B input capture/compare match	Not possible	Possible	=
	TCI5V	TCNT5 overflow	Not possible	Not possible	=
	TCI5U	TCNT5 underflow	Not possible	Not possible	Low

Note: This table shows the initial state immediately after a reset. The relative channel priorities can be changed by the interrupt controller.

Input Capture/Compare Match Interrupt: An interrupt is requested if the TGIE bit in TIER is set to 1 when the TGF flag in TSR is set to 1 by the occurrence of a TGR input capture/compare match on a particular channel. The interrupt request is cleared by clearing the TGF flag to 0. The TPU has 16 input capture/compare match interrupts, four each for channels 0 and 3, and two each for channels 1, 2, 4, and 5.

Overflow Interrupt: An interrupt is requested if the TCIEV bit in TIER is set to 1 when the TCFV flag in TSR is set to 1 by the occurrence of TCNT overflow on a channel. The interrupt request is cleared by clearing the TCFV flag to 0. The TPU has six overflow interrupts, one for each channel.

Underflow Interrupt: An interrupt is requested if the TCIEU bit in TIER is set to 1 when the TCFU flag in TSR is set to 1 by the occurrence of TCNT underflow on a channel. The interrupt request is cleared by clearing the TCFU flag to 0. The TPU has four underflow interrupts, one each for channels 1, 2, 4, and 5.

10.5.2 DTC/DMAC Activation

DTC Activation: The DTC can be activated by the TGR input capture/compare match interrupt for a channel. For details, see section 8, Data Transfer Controller.

A total of 16 TPU input capture/compare match interrupts can be used as DTC activation sources, four each for channels 0 and 3, and two each for channels 1, 2, 4, and 5.

DMAC Activation: The DMAC can be activated by the TGRA input capture/compare match interrupt for a channel. For details, see section 7, DMA Controller.

In the TPU, a total of six TGRA input capture/compare match interrupts can be used as DMAC activation sources, one for each channel.

10.5.3 A/D Converter Activation

The A/D converter can be activated by the TGRA input capture/compare match for a channel.

If the TTGE bit in TIER is set to 1 when the TGFA flag in TSR is set to 1 by the occurrence of a TGRA input capture/compare match on a particular channel, a request to start A/D conversion is sent to the A/D converter. If the TPU conversion start trigger has been selected on the A/D converter side at this time, A/D conversion is started.

In the TPU, a total of six TGRA input capture/compare match interrupts can be used as A/D converter conversion start sources, one for each channel.

10.6 Operation Timing

10.6.1 Input/Output Timing

TCNT Count Timing: Figure 10-34 shows TCNT count timing in internal clock operation, and figure 10-35 shows TCNT count timing in external clock operation.

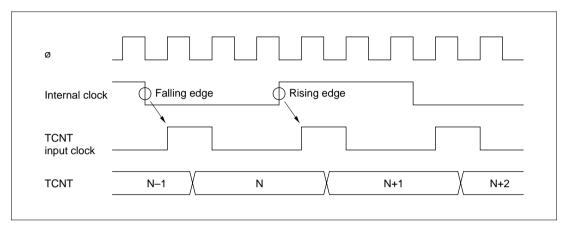


Figure 10-34 Count Timing in Internal Clock Operation

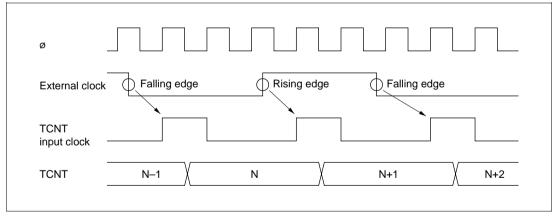


Figure 10-35 Count Timing in External Clock Operation

Output Compare Output Timing: A compare match signal is generated in the final state in which TCNT and TGR match (the point at which the count value matched by TCNT is updated). When a compare match signal is generated, the output value set in TIOR is output at the output compare output pin. After a match between TCNT and TGR, the compare match signal is not generated until the TCNT input clock is generated.

Figure 10-36 shows output compare output timing.

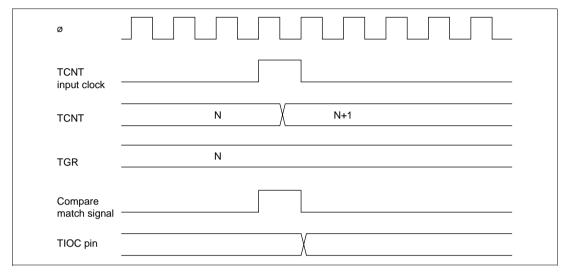


Figure 10-36 Output Compare Output Timing

Input Capture Signal Timing: Figure 10-37 shows input capture signal timing.

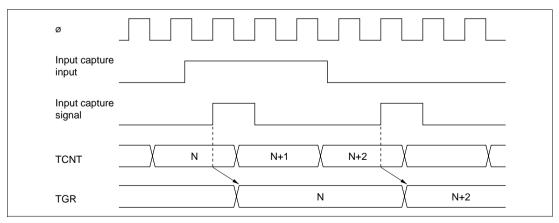


Figure 10-37 Input Capture Input Signal Timing

Timing for Counter Clearing by Compare Match/Input Capture: Figure 10-38 shows the timing when counter clearing by compare match occurrence is specified, and figure 10-39 shows the timing when counter clearing by input capture occurrence is specified.

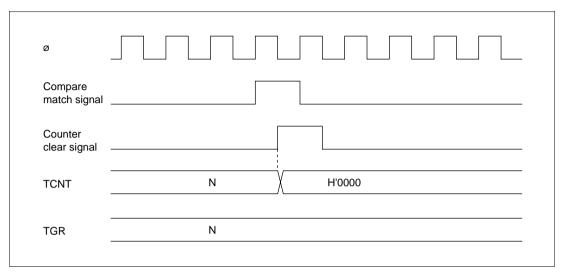


Figure 10-38 Counter Clear Timing (Compare Match)

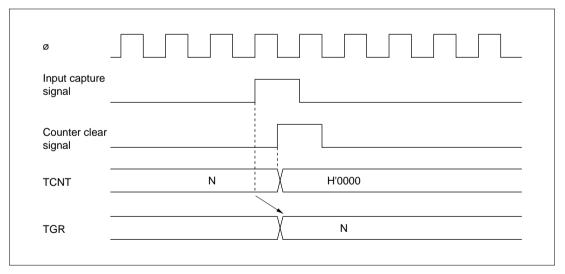


Figure 10-39 Counter Clear Timing (Input Capture)

Buffer Operation Timing: Figures 10-40 and 10-41 show the timing in buffer operation.

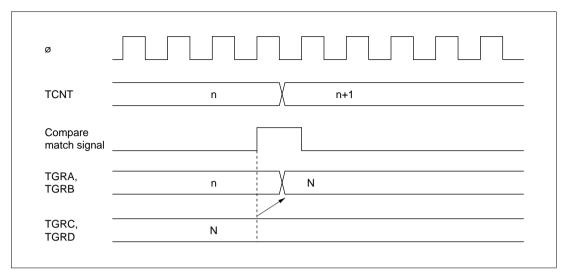


Figure 10-40 Buffer Operation Timing (Compare Match)

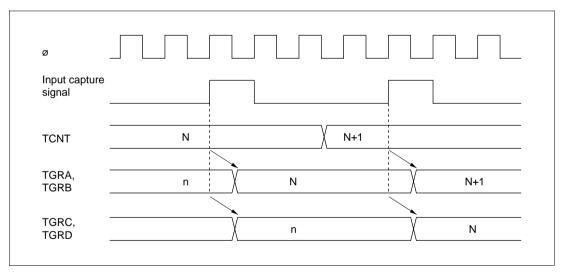


Figure 10-41 Buffer Operation Timing (Input Capture)

10.6.2 Interrupt Signal Timing

TGF Flag Setting Timing in Case of Compare Match: Figure 10-42 shows the timing for setting of the TGF flag in TSR by compare match occurrence, and TGI interrupt request signal timing.

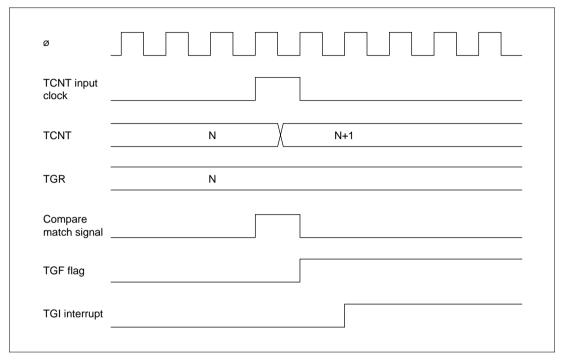


Figure 10-42 TGI Interrupt Timing (Compare Match)

TGF Flag Setting Timing in Case of Input Capture: Figure 10-43 shows the timing for setting of the TGF flag in TSR by input capture occurrence, and TGI interrupt request signal timing.

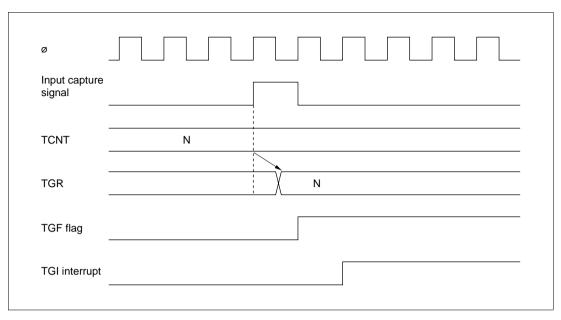


Figure 10-43 TGI Interrupt Timing (Input Capture)

TCFV Flag/TCFU Flag Setting Timing: Figure 10-44 shows the timing for setting of the TCFV flag in TSR by overflow occurrence, and TCIV interrupt request signal timing.

Figure 10-45 shows the timing for setting of the TCFU flag in TSR by underflow occurrence, and TCIU interrupt request signal timing.

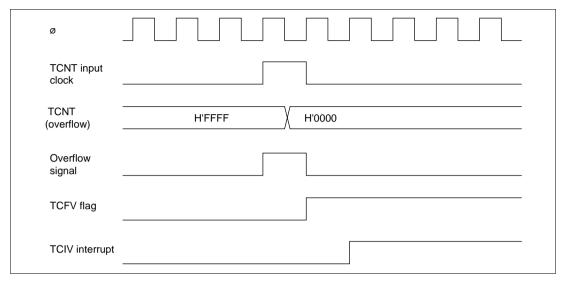


Figure 10-44 TCIV Interrupt Setting Timing

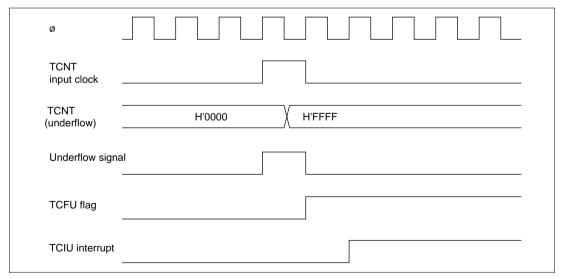


Figure 10-45 TCIU Interrupt Setting Timing

Status Flag Clearing Timing: After a status flag is read as 1 by the CPU, it is cleared by writing 0 to it. When the DTC or DMAC is activated, the flag is cleared automatically. Figure 10-46 shows the timing for status flag clearing by the CPU, and figure 10-47 shows the timing for status flag clearing by the DTC or DMAC.

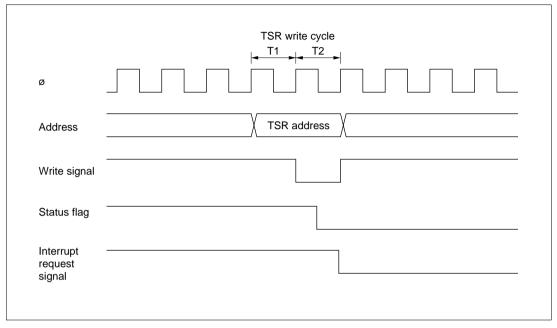


Figure 10-46 Timing for Status Flag Clearing by CPU

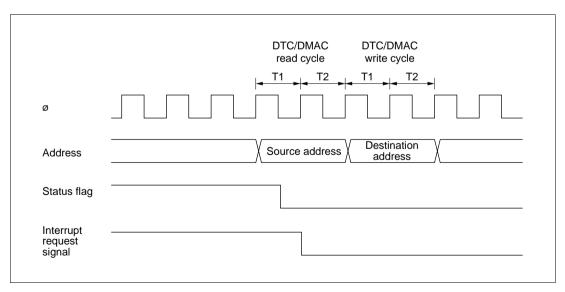


Figure 10-47 Timing for Status Flag Clearing by DTC/DMAC Activation

10.7 Usage Notes

Note that the kinds of operation and contention described below occur during TPU operation.

Input Clock Restrictions: The input clock pulse width must be at least 1.5 states in the case of single-edge detection, and at least 2.5 states in the case of both-edge detection. The TPU will not operate properly with a narrower pulse width.

In phase counting mode, the phase difference and overlap between the two input clocks must be at least 1.5 states, and the pulse width must be at least 2.5 states. Figure 10-48 shows the input clock conditions in phase counting mode.

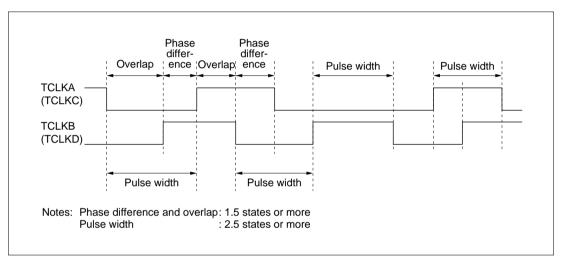


Figure 10-48 Phase Difference, Overlap, and Pulse Width in Phase Counting Mode

Caution on Period Setting: When counter clearing by compare match is set, TCNT is cleared in the final state in which it matches the TGR value (the point at which the count value matched by TCNT is updated). Consequently, the actual counter frequency is given by the following formula:

$$f = \frac{\emptyset}{(N+1)}$$

Where f : Counter frequency

 ϕ : Operating frequency

N: TGR set value

Contention between TCNT Write and Clear Operations: If the counter clear signal is generated in the T2 state of a TCNT write cycle, TCNT clearing takes precedence and the TCNT write is not performed.

Figure 10-49 shows the timing in this case.

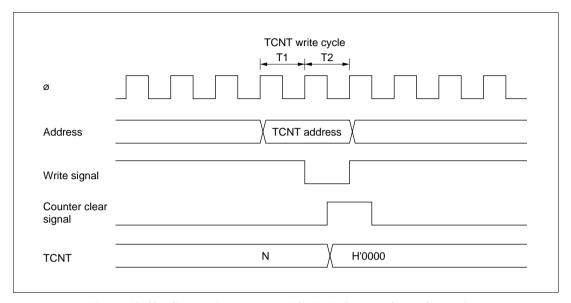


Figure 10-49 Contention between TCNT Write and Clear Operations

Contention between TCNT Write and Increment Operations: If incrementing occurs in the T2 state of a TCNT write cycle, the TCNT write takes precedence and TCNT is not incremented.

Figure 10-50 shows the timing in this case.

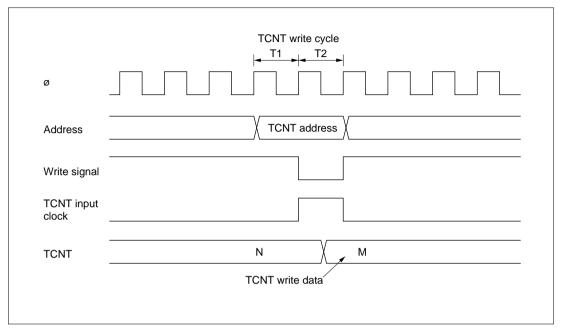


Figure 10-50 Contention between TCNT Write and Increment Operations

Contention between TGR Write and Compare Match: If a compare match occurs in the T2 state of a TGR write cycle, the TGR write takes precedence and the compare match signal is inhibited. A compare match does not occur even if the same value as before is written.

Figure 10-51 shows the timing in this case.

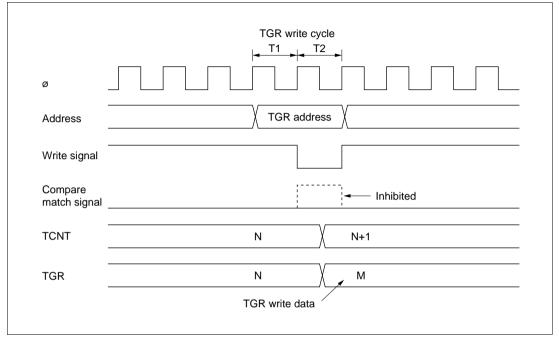


Figure 10-51 Contention between TGR Write and Compare Match

Contention between Buffer Register Write and Compare Match: If a compare match occurs in the T2 state of a TGR write cycle, the data transferred to TGR by the buffer operation will be the data prior to the write.

Figure 10-52 shows the timing in this case.

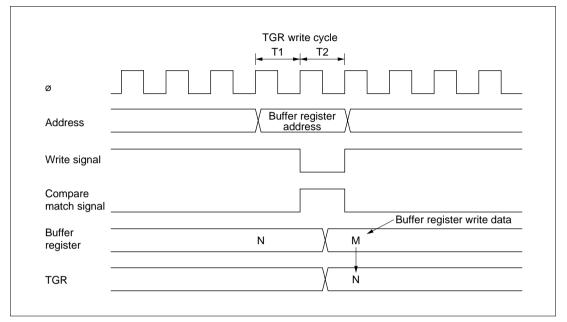


Figure 10-52 Contention between Buffer Register Write and Compare Match

Contention between TGR Read and Input Capture: If the input capture signal is generated in the T1 state of a TGR read cycle, the data that is read will be the data after input capture transfer.

Figure 10-53 shows the timing in this case.

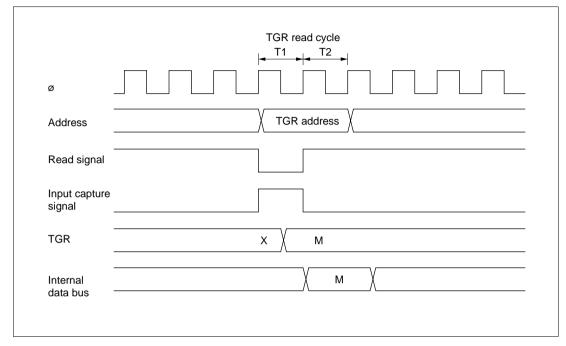


Figure 10-53 Contention between TGR Read and Input Capture

Contention between TGR Write and Input Capture: If the input capture signal is generated in the T2 state of a TGR write cycle, the input capture operation takes precedence and the write to TGR is not performed.

Figure 10-54 shows the timing in this case.

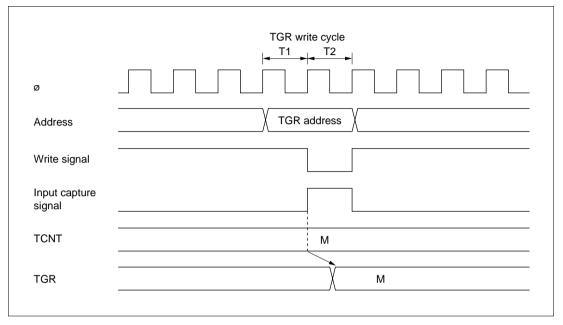


Figure 10-54 Contention between TGR Write and Input Capture

Contention between Buffer Register Write and Input Capture: If the input capture signal is generated in the T2 state of a buffer write cycle, the buffer operation takes precedence and the write to the buffer register is not performed.

Figure 10-55 shows the timing in this case.

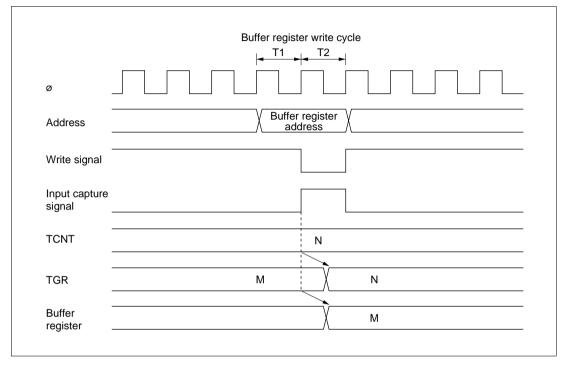


Figure 10-55 Contention between Buffer Register Write and Input Capture

Contention between Overflow/Underflow and Counter Clearing: If overflow/underflow and counter clearing occur simultaneously, the TCFV/TCFU flag in TSR is not set and TCNT clearing takes precedence.

Figure 10-56 shows the operation timing when a TGR compare match is specified as the clearing source, and H'FFFF is set in TGR.

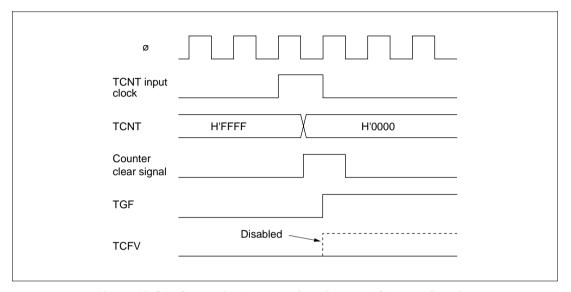


Figure 10-56 Contention between Overflow and Counter Clearing

Contention between TCNT Write and Overflow/Underflow: If there is an up-count or down-count in the T2 state of a TCNT write cycle, and overflow/underflow occurs, the TCNT write takes precedence and the TCFV/TCFU flag in TSR is not set.

Figure 10-57 shows the operation timing when there is contention between TCNT write and overflow.

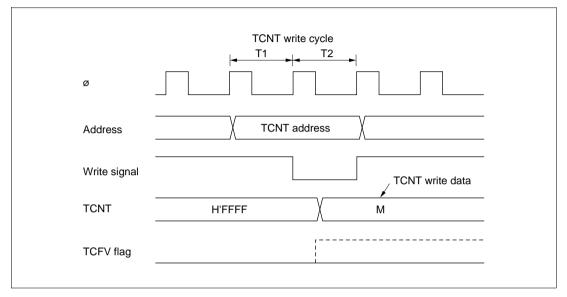


Figure 10-57 Contention between TCNT Write and Overflow

Multiplexing of I/O Pins: In the H8S/2357 Series, the TCLKA input pin is multiplexed with the TIOCC0 I/O pin, the TCLKB input pin with the TIOCD0 I/O pin, the TCLKC input pin with the TIOCB1 I/O pin, and the TCLKD input pin with the TIOCB2 I/O pin. When an external clock is input, compare match output should not be performed from a multiplexed pin.

Interrupts and Module Stop Mode: If module stop mode is entered when an interrupt has been requested, it will not be possible to clear the CPU interrupt source or the DMAC or DTC activation source. Interrupts should therefore be disabled before entering module stop mode.

Section 11 Programmable Pulse Generator (PPG)

11.1 Overview

The H8S/2357 Series has a built-in programmable pulse generator (PPG) that provides pulse outputs by using the 16-bit timer-pulse unit (TPU) as a time base. The PPG pulse outputs are divided into 4-bit groups (group 3 to group 0) that can operate both simultaneously and independently.

11.1.1 Features

PPG features are listed below.

- 16-bit output data
 - Maximum 16-bit data can be output, and output can be enabled on a bit-by-bit basis
- Four output groups
 - Output trigger signals can be selected in 4-bit groups to provide up to four different 4-bit outputs
- Selectable output trigger signals
 - Output trigger signals can be selected for each group from the compare match signals of four TPU channels
- Non-overlap mode
 - A non-overlap margin can be provided between pulse outputs
- Can operate together with the data transfer controller (DTC) and DMA controller (DMAC)
 - The compare match signals selected as output trigger signals can activate the DTC or DMAC for sequential output of data without CPU intervention
- Settable inverted output
 - Inverted data can be output for each group
- Module stop mode can be set
 - As the initial setting, PPG operation is halted. Register access is enabled by exiting module stop mode

11.1.2 Block Diagram

Figure 11-1 shows a block diagram of the PPG.

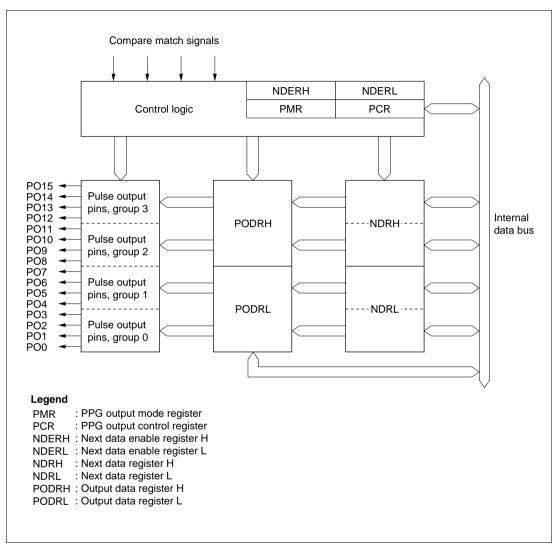


Figure 11-1 Block Diagram of PPG

11.1.3 Pin Configuration

Table 11-1 summarizes the PPG pins.

Table 11-1 PPG Pins

Name	Symbol	I/O	Function
Pulse output 0	PO0	Output	Group 0 pulse output
Pulse output 1	PO1	Output	
Pulse output 2	PO2	Output	
Pulse output 3	PO3	Output	
Pulse output 4	PO4	Output	Group 1 pulse output
Pulse output 5	PO5	Output	
Pulse output 6	PO6	Output	
Pulse output 7	PO7	Output	
Pulse output 8	PO8	Output	Group 2 pulse output
Pulse output 9	PO9	Output	
Pulse output 10	PO10	Output	
Pulse output 11	PO11	Output	
Pulse output 12	PO12	Output	Group 3 pulse output
Pulse output 13	PO13	Output	
Pulse output 14	PO14	Output	
Pulse output 15	PO15	Output	

11.1.4 Registers

Table 11-2 summarizes the PPG registers.

Table 11-2 PPG Registers

Name	Abbreviation	R/W	Initial Value	Address*1
PPG output control register	PCR	R/W	H'FF	H'FF46
PPG output mode register	PMR	R/W	H'F0	H'FF47
Next data enable register H	NDERH	R/W	H'00	H'FF48
Next data enable register L	NDERL	R/W	H'00	H'FF49
Output data register H	PODRH	R/(W)*2	H'00	H'FF4A
Output data register L	PODRL	R/(W)*2	H'00	H'FF4B
Next data register H	NDRH	R/W	H'00	H'FF4C* ³ H'FF4E
Next data register L	NDRL	R/W	H'00	H'FF4D* ³ H'FF4F
Port 1 data direction register	P1DDR	W	H'00	H'FEB0
Port 2 data direction register	P2DDR	W	H'00	H'FEB1
Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address.

- 2. Bits used for pulse output cannot be written to.
- When the same output trigger is selected for pulse output groups 2 and 3 by the PCR setting, the NDRH address is H'FF4C. When the output triggers are different, the NDRH address is H'FF4E for group 2 and H'FF4C for group 3.

Similarly, when the same output trigger is selected for pulse output groups 0 and 1 by the PCR setting, the NDRL address is H'FF4D. When the output triggers are different, the NDRL address is H'FF4F for group 0 and H'FF4D for group 1.

11.2 Register Descriptions

11.2.1 Next Data Enable Registers H and L (NDERH, NDERL)

NDERH

Bit :	7	6	5	4	3	2	1	0
	NDER15	NDER14	NDER13	NDER12	NDER11	NDER10	NDER9	NDER8
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W R/W							
NDERL								
Bit :	7	6	5	4	3	2	1	0
	NDER7	NDER6	NDER5	NDER4	NDER3	NDER2	NDER1	NDER0
Initial value:	0	0	0	0	0	0	0	0
R/W :	R/W R/W							

NDERH and NDERL are 8-bit readable/writable registers that enable or disable pulse output on a bit-by-bit basis.

If a bit is enabled for pulse output by NDERH or NDERL, the NDR value is automatically transferred to the corresponding PODR bit when the TPU compare match event specified by PCR occurs, updating the output value. If pulse output is disabled, the bit value is not transferred from NDR to PODR and the output value does not change.

NDERH and NDERL are each initialized to H'00 by a reset and in hardware standby mode. They are not initialized in software standby mode.

NDERH Bits 7 to 0—Next Data Enable 15 to 8 (NDER15 to NDER8): These bits enable or disable pulse output on a bit-by-bit basis.

Bits 7 to 0	
NDER15 to NDER8	Description

0	Pulse outputs PO15 to PO8 are disabled (NDR15 to NDR8 are not					
	transferred to POD15 to POD8)	(Initial value)				
1	Pulse outputs PO15 to PO8 are enabled (NDR15 to to POD15 to POD8)	NDR8 are transferred				

NDERL Bits 7 to 0—Next Data Enable 7 to 0 (NDER7 to NDER0): These bits enable or disable pulse output on a bit-by-bit basis.

Bits 7 to 0 NDER7 to NDER0	Description	
0	Pulse outputs PO7 to PO0 are disabled (NDR7 to N transferred to POD7 to POD0)	IDR0 are not (Initial value)
1	Pulse outputs PO7 to PO0 are enabled (NDR7 to N POD7 to POD0)	DR0 are transferred to

11.2.2 Output Data Registers H and L (PODRH, PODRL)

PODRH

Bit	:	7	6	5	4	3	2	1	0
		POD15	POD14	POD13	POD12	POD11	POD10	POD9	POD8
Initial value	:	0	0	0	0	0	0	0	0
R/W	:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*

PODRL

Bit	:	7	6	5	4	3	2	1	0
		POD7	POD6	POD5	POD4	POD3	POD2	POD1	POD0
Initial value	э:	0	0	0	0	0	0	0	0
R/W	:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*

Note: * A bit that has been set for pulse output by NDER is read-only.

PODRH and PODRL are 8-bit readable/writable registers that store output data for use in pulse output.

11.2.3 Next Data Registers H and L (NDRH, NDRL)

NDRH and NDRL are 8-bit readable/writable registers that store the next data for pulse output. During pulse output, the contents of NDRH and NDRL are transferred to the corresponding bits in PODRH and PODRL when the TPU compare match event specified by PCR occurs. The NDRH and NDRL addresses differ depending on whether pulse output groups have the same output trigger or different output triggers. For details see section 11.2.4, Notes on NDR Access.

NDRH and NDRL are each initialized to H'00 by a reset and in hardware standby mode. They are not initialized in software standby mode.

11.2.4 Notes on NDR Access

The NDRH and NDRL addresses differ depending on whether pulse output groups have the same output trigger or different output triggers.

Same Trigger for Pulse Output Groups: If pulse output groups 2 and 3 are triggered by the same compare match event, the NDRH address is H'FF4C. The upper 4 bits belong to group 3 and the lower 4 bits to group 2. Address H'FF4E consists entirely of reserved bits that cannot be modified and are always read as 1.

Address H'FF4C

Bit	:	7	6	5	4	3	2	1	0
		NDR15	NDR14	NDR13	NDR12	NDR11	NDR10	NDR9	NDR8
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W R/W							

Address H'FF4E

Bit	:	7	6	5	4	3	2	1	0	
		_	_	_	_	_	_	_	_	Ī
Initial val	lue :	1	1	1	1	1	1	1	1	
R/W	:	_	_	_	_	_	_	_	_	

If pulse output groups 0 and 1 are triggered by the same compare match event, the NDRL address is H'FF4D. The upper 4 bits belong to group 1 and the lower 4 bits to group 0. Address H'FF4F consists entirely of reserved bits that cannot be modified and are always read as 1.

Address H'FF4D

Bit	:	7	6	5	4	3	2	1	0
		NDR7	NDR6	NDR5	NDR4	NDR3	NDR2	NDR1	NDR0
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W							

Address H'FF4F

Bit	:	7	6	5	4	3	2	1	0
		_		_	_	_		_	_
Initial va	alue :	1	1	1	1	1	1	1	1
R/W	:	_	_	_	_	_	_	_	_

Different Triggers for Pulse Output Groups: If pulse output groups 2 and 3 are triggered by different compare match events, the address of the upper 4 bits in NDRH (group 3) is H'FF4C and the address of the lower 4 bits (group 2) is H'FF4E. Bits 3 to 0 of address H'FF4C and bits 7 to 4 of address H'FF4E are reserved bits that cannot be modified and are always read as 1.

Address H'FF4C

Bit	:	7	6	5	4	3	2	1	0
		NDR15	NDR14	NDR13	NDR12	_	_	_	_
Initial va	alue :	0	0	0	0	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	_	_	_	_

Address H'FF4E

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	NDR11	NDR10	NDR9	NDR8
Initial va	alue :	1	1	1	1	0	0	0	0
R/W	:	_	_	_	_	R/W	R/W	R/W	R/W

If pulse output groups 0 and 1 are triggered by different compare match event, the address of the upper 4 bits in NDRL (group 1) is H'FF4D and the address of the lower 4 bits (group 0) is H'FF4F. Bits 3 to 0 of address H'FF4D and bits 7 to 4 of address H'FF4F are reserved bits that cannot be modified and are always read as 1.

Address H'FF4D

Bit	:	7	6	5	4	3	2	1	0
		NDR7	NDR6	NDR5	NDR4	_	_		_
Initial v	alue :	0	0	0	0	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	_	_	_	_

Address H'FF4F

Bit	:	7	6	5	4	3	2	1	0
	-	_	_	_	_	NDR3	NDR2	NDR1	NDR0
Initial va	lue :	1	1	1	1	0	0	0	0
R/W	:	_	_	_	_	R/W	R/W	R/W	R/W

11.2.5 PPG Output Control Register (PCR)

Bit :	7	6	5	4	3	2	1	0
	G3CMS1	G3CMS0	G2CMS1	G2CMS0	G1CMS1	G1CMS0	G0CMS1	G0CMS0
Initial value:	1	1	1	1	1	1	1	1
R/W :	R/W							

PCR is an 8-bit readable/writable register that selects output trigger signals for PPG outputs on a group-by-group basis.

PCR is initialized to H'FF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bits 7 and 6—Group 3 Compare Match Select 1 and 0 (G3CMS1, G3CMS0): These bits select the compare match that triggers pulse output group 3 (pins PO15 to PO12).

		Description					
Bit 7 G3CMS1	Bit 6 G3CMS0	Output Trigger for Pulse Output Group 3					
0	0	Compare match in TPU channel 0					
	1	Compare match in TPU channel 1					
1	0	Compare match in TPU channel 2					
	1	Compare match in TPU channel 3	(Initial value)				

Bits 5 and 4—Group 2 Compare Match Select 1 and 0 (G2CMS1, G2CMS0): These bits select the compare match that triggers pulse output group 2 (pins PO11 to PO8).

		Description					
Bit 5 G2CMS1	Bit 4 G2CMS0	Output Trigger for Pulse Output Group 2					
0	0	Compare match in TPU channel 0					
	1	Compare match in TPU channel 1					
1	0	Compare match in TPU channel 2					
	1	Compare match in TPU channel 3	(Initial value)				

Bits 3 and 2—Group 1 Compare Match Select 1 and 0 (G1CMS1, G1CMS0): These bits select the compare match that triggers pulse output group 1 (pins PO7 to PO4).

		Description						
Bit 3 G1CMS1	Bit 2 G1CMS0	Output Trigger for Pulse Output Group 1						
0	0	Compare match in TPU channel 0	_					
	1	Compare match in TPU channel 1						
1	0	Compare match in TPU channel 2						
	1	Compare match in TPU channel 3	(Initial value)					

Bits 1 and 0—Group 0 Compare Match Select 1 and 0 (G0CMS1, G0CMS0): These bits select the compare match that triggers pulse output group 0 (pins PO3 to PO0).

		Description						
Bit 1 G0CMS1	Bit 0 G0CMS0	Output Trigger for Pulse Output Group 0						
0	0	Compare match in TPU channel 0						
	1	Compare match in TPU channel 1	_					
1	0	Compare match in TPU channel 2						
	1	Compare match in TPU channel 3	(Initial value)					

11.2.6 PPG Output Mode Register (PMR)

Bit	:	7	6	5	4	3	2	1	0
		G3INV	G2INV	G1INV	G0INV	G3NOV	G2NOV	G1NOV	G0NOV
Initial va	lue :	1	1	1	1	0	0	0	0
R/W	:	R/W							

PMR is an 8-bit readable/writable register that selects pulse output inversion and non-overlapping operation for each group.

The output trigger period of a non-overlapping operation PPG output waveform is set in TGRB and the non-overlap margin is set in TGRA. The output values change at compare match A and B.

For details, see section 11.3.4, Non-Overlapping Pulse Output.

PMR is initialized to H'F0 by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 7—Group 3 Inversion (G3INV): Selects direct output or inverted output for pulse output group 3 (pins PO15 to PO12).

Bit 7 G3INV	Description
0	Inverted output for pulse output group 3 (low-level output at pin for a 1 in PODRH)
1	Direct output for pulse output group 3 (high-level output at pin for a 1 in PODRH) (Initial value)

Bit 6—Group 2 Inversion (G2INV): Selects direct output or inverted output for pulse output group 2 (pins PO11 to PO8).

Bit 6 G2INV	Description
0	Inverted output for pulse output group 2 (low-level output at pin for a 1 in PODRH)
1	Direct output for pulse output group 2 (high-level output at pin for a 1 in PODRH) (Initial value)

Bit 5—Group 1 Inversion (G1INV): Selects direct output or inverted output for pulse output group 1 (pins PO7 to PO4).

Bit 5 G1INV	Description
0	Inverted output for pulse output group 1 (low-level output at pin for a 1 in PODRL)
1	Direct output for pulse output group 1 (high-level output at pin for a 1 in PODRL) (Initial value)

Bit 4—Group 0 Inversion (G0INV): Selects direct output or inverted output for pulse output group 0 (pins PO3 to PO0).

Bit 4 G0INV	Description
0	Inverted output for pulse output group 0 (low-level output at pin for a 1 in PODRL)
1	Direct output for pulse output group 0 (high-level output at pin for a 1 in PODRL) (Initial value)

Bit 3—Group 3 Non-Overlap (G3NOV): Selects normal or non-overlapping operation for pulse output group 3 (pins PO15 to PO12).

Bit 3 G3NOV	Description
0	Normal operation in pulse output group 3 (output values updated at compare match A in the selected TPU channel) (Initial value)
1	Non-overlapping operation in pulse output group 3 (independent 1 and 0 output at compare match A or B in the selected TPU channel)

Bit 2—Group 2 Non-Overlap (G2NOV): Selects normal or non-overlapping operation for pulse output group 2 (pins PO11 to PO8).

Bit 2 G2NOV	Description
0	Normal operation in pulse output group 2 (output values updated at compare match A in the selected TPU channel) (Initial value)
1	Non-overlapping operation in pulse output group 2 (independent 1 and 0 output at compare match A or B in the selected TPU channel)

Bit 1—Group 1 Non-Overlap (G1NOV): Selects normal or non-overlapping operation for pulse output group 1 (pins PO7 to PO4).

Bit 1 G1NOV	Description
0	Normal operation in pulse output group 1 (output values updated at compare match A in the selected TPU channel) (Initial value)
1	Non-overlapping operation in pulse output group 1 (independent 1 and 0 output at compare match A or B in the selected TPU channel)

Bit 0—Group 0 Non-Overlap (G0NOV): Selects normal or non-overlapping operation for pulse output group 0 (pins PO3 to PO0).

Bit 0 G0NOV	Description
0	Normal operation in pulse output group 0 (output values updated at compare match A in the selected TPU channel) (Initial value)
1	Non-overlapping operation in pulse output group 0 (independent 1 and 0 output at compare match A or B in the selected TPU channel)

11.2.7 Port 1 Data Direction Register (P1DDR)

Bit	:	7	6	5	4	3	2	1	0
		P17DDR	P16DDR	P15DDR	P14DDR	P13DDR	P12DDR	P11DDR	P10DDR
Initial valu	e :	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

P1DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 1.

Port 1 is multiplexed with pins PO15 to PO8. Bits corresponding to pins used for PPG output must be set to 1. For further information about P1DDR, see section 9.2, Port 1.

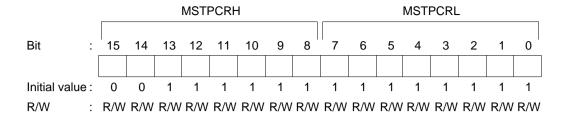
11.2.8 Port 2 Data Direction Register (P2DDR)

Bit	:	7	6	5	4	3	2	1	0
		P27DDR	P26DDR	P25DDR	P24DDR	P23DDR	P22DDR	P21DDR	P20DDR
Initial valu	ue:	0	0	0	0	0	0	0	0
R/W	:	W	W	W	W	W	W	W	W

P2DDR is an 8-bit write-only register, the individual bits of which specify input or output for the pins of port 2.

Port 2 is multiplexed with pins PO7 to PO0. Bits corresponding to pins used for PPG output must be set to 1. For further information about P2DDR, see section 9.3, Port 2.

11.2.9 Module Stop Control Register (MSTPCR)



MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP11 bit in MSTPCR is set to 1, PPG operation stops at the end of the bus cycle and a transition is made to module stop mode. Registers cannot be read or written to in module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 11—Module Stop (MSTP11): Specifies the PPG module stop mode.

Bit 11 MSTP11 Description

0	PPG module stop mode cleared	
1	PPG module stop mode set	(Initial value)

11.3 Operation

11.3.1 Overview

PPG pulse output is enabled when the corresponding bits in P1DDR, P2DDR, and NDER are set to 1. In this state the corresponding PODR contents are output.

When the compare match event specified by PCR occurs, the corresponding NDR bit contents are transferred to PODR to update the output values.

Figure 11-2 illustrates the PPG output operation and table 11-3 summarizes the PPG operating conditions.

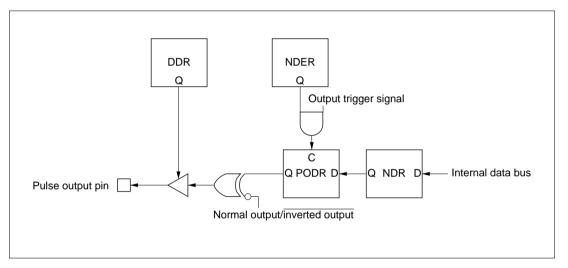


Figure 11-2 PPG Output Operation

Table 11-3 PPG Operating Conditions

NDER	DDR	Pin Function
0	0	Generic input port
	1	Generic output port
1	0	Generic input port (but the PODR bit is a read-only bit, and when compare match occurs, the NDR bit value is transferred to the PODR bit)
	1	PPG pulse output

Sequential output of data of up to 16 bits is possible by writing new output data to NDR before the next compare match. For details of non-overlapping operation, see section 11.3.4, Non-Overlapping Pulse Output.

11.3.2 Output Timing

If pulse output is enabled, NDR contents are transferred to PODR and output when the specified compare match event occurs. Figure 11-3 shows the timing of these operations for the case of normal output in groups 2 and 3, triggered by compare match A.

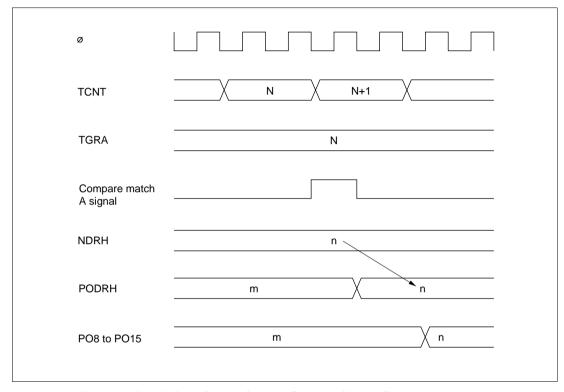


Figure 11-3 Timing of Transfer and Output of NDR Contents (Example)

11.3.3 Normal Pulse Output

Sample Setup Procedure for Normal Pulse Output: Figure 11-4 shows a sample procedure for setting up normal pulse output.

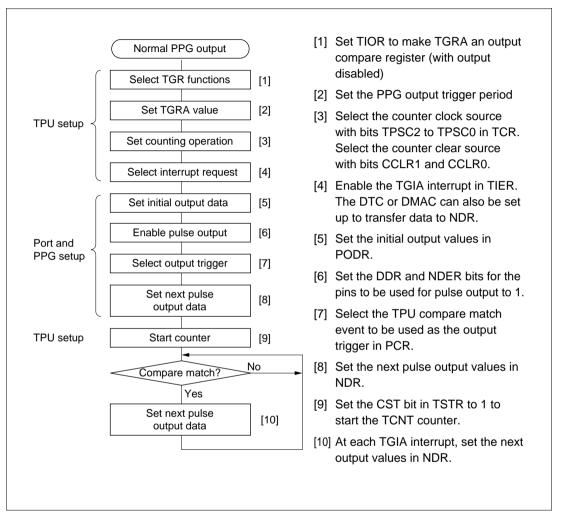


Figure 11-4 Setup Procedure for Normal Pulse Output (Example)

Example of Normal Pulse Output (Example of Five-Phase Pulse Output): Figure 11-5 shows an example in which pulse output is used for cyclic five-phase pulse output.

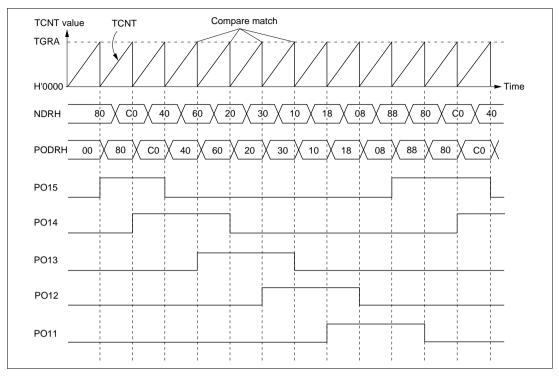


Figure 11-5 Normal Pulse Output Example (Five-Phase Pulse Output)

- [1] Set up the TPU channel to be used as the output trigger channel so that TGRA is an output compare register and the counter will be cleared by compare match A. Set the trigger period in TGRA and set the TGIEA bit in TIER to 1 to enable the compare match A (TGIA) interrupt.
- [2] Write H'F8 in P1DDR and NDERH, and set the G3CMS1, G3CMS0, G2CMS1, and G2CMS0 bits in PCR to select compare match in the TPU channel set up in the previous step to be the output trigger. Write output data H'80 in NDRH.
- [3] The timer counter in the TPU channel starts. When compare match A occurs, the NDRH contents are transferred to PODRH and output. The TGIA interrupt handling routine writes the next output data (H'C0) in NDRH.
- [4] Five-phase overlapping pulse output (one or two phases active at a time) can be obtained subsequently by writing H'40, H'60, H'20, H'30. H'10, H'18, H'08, H'88... at successive TGIA interrupts. If the DTC or DMAC is set for activation by this interrupt, pulse output can be obtained without imposing a load on the CPU.

11.3.4 Non-Overlapping Pulse Output

Sample Setup Procedure for Non-Overlapping Pulse Output: Figure 11-6 shows a sample procedure for setting up non-overlapping pulse output.

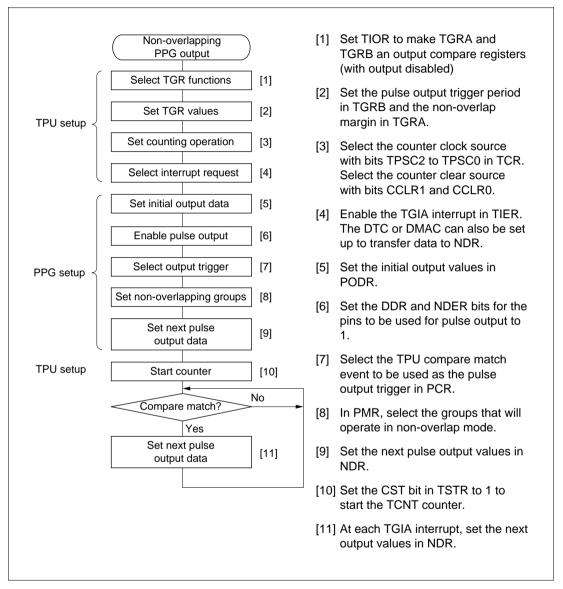


Figure 11-6 Setup Procedure for Non-Overlapping Pulse Output (Example)

Example of Non-Overlapping Pulse Output (Example of Four-Phase Complementary Non-Overlapping Output): Figure 11-7 shows an example in which pulse output is used for four-phase complementary non-overlapping pulse output.

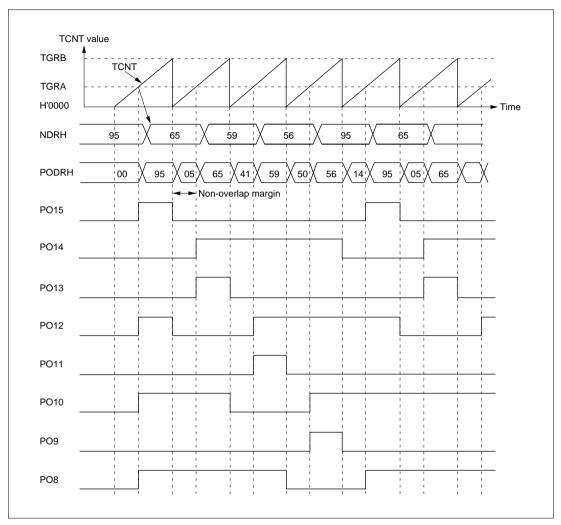


Figure 11-7 Non-Overlapping Pulse Output Example (Four-Phase Complementary)

- [1] Set up the TPU channel to be used as the output trigger channel so that TGRA and TGRB are output compare registers. Set the trigger period in TGRB and the non-overlap margin in TGRA, and set the counter to be cleared by compare match B. Set the TGIEA bit in TIER to 1 to enable the TGIA interrupt.
- [2] Write H'FF in P1DDR and NDERH, and set the G3CMS1, G3CMS0, G2CMS1, and G2CMS0 bits in PCR to select compare match in the TPU channel set up in the previous step to be the output trigger. Set the G3NOV and G2NOV bits in PMR to 1 to select non-overlapping output. Write output data H'95 in NDRH.
- [3] The timer counter in the TPU channel starts. When a compare match with TGRB occurs, outputs change from 1 to 0. When a compare match with TGRA occurs, outputs change from 0 to 1 (the change from 0 to 1 is delayed by the value set in TGRA). The TGIA interrupt handling routine writes the next output data (H'65) in NDRH.
- [4] Four-phase complementary non-overlapping pulse output can be obtained subsequently by writing H'59, H'56, H'95... at successive TGIA interrupts. If the DTC or DMAC is set for activation by this interrupt, pulse output can be obtained without imposing a load on the CPU.

11.3.5 Inverted Pulse Output

If the G3INV, G2INV, G1INV, and G0INV bits in PMR are cleared to 0, values that are the inverse of the PODR contents can be output.

Figure 11-8 shows the outputs when G3INV and G2INV are cleared to 0, in addition to the settings of figure 11-7.

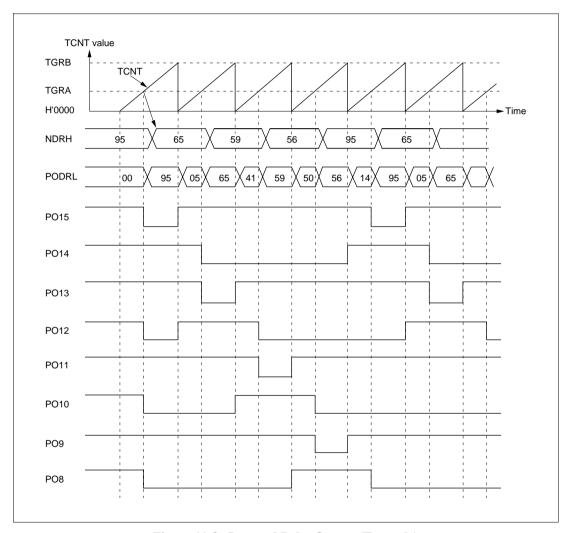


Figure 11-8 Inverted Pulse Output (Example)

11.3.6 Pulse Output Triggered by Input Capture

Pulse output can be triggered by TPU input capture as well as by compare match. If TGRA functions as an input capture register in the TPU channel selected by PCR, pulse output will be triggered by the input capture signal.

Figure 11-9 shows the timing of this output.

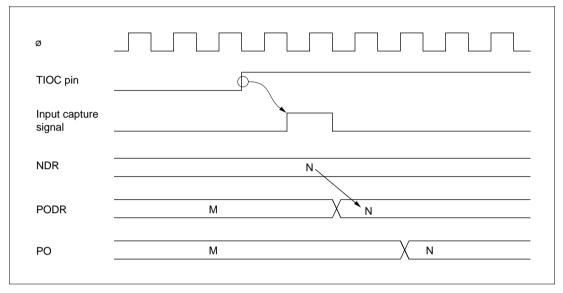


Figure 11-9 Pulse Output Triggered by Input Capture (Example)

11.4 Usage Notes

Operation of Pulse Output Pins: Pins PO0 to PO15 are also used for other peripheral functions such as the TPU. When output by another peripheral function is enabled, the corresponding pins cannot be used for pulse output. Note, however, that data transfer from NDR bits to PODR bits takes place, regardless of the usage of the pins.

Pin functions should be changed only under conditions in which the output trigger event will not occur.

Note on Non-Overlapping Output: During non-overlapping operation, the transfer of NDR bit values to PODR bits takes place as follows.

- NDR bits are always transferred to PODR bits at compare match A.
- At compare match B, NDR bits are transferred only if their value is 0. Bits are not transferred if their value is 1.

Figure 11-10 illustrates the non-overlapping pulse output operation.

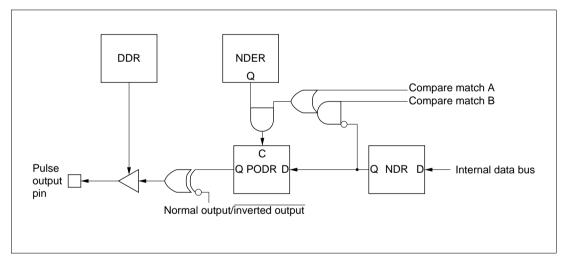


Figure 11-10 Non-Overlapping Pulse Output

Therefore, 0 data can be transferred ahead of 1 data by making compare match B occur before compare match A. The NDR contents should not be altered during the interval from compare match B to compare match A (the non-overlap margin).

This can be accomplished by having the TGIA interrupt handling routine write the next data in NDR, or by having the TGIA interrupt activate the DTC or DMAC. Note, however, that the next data must be written before the next compare match B occurs.

Figure 11-11 shows the timing of this operation.

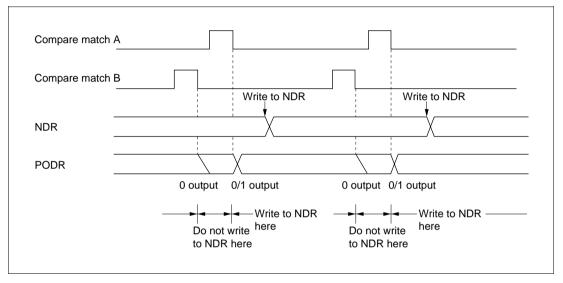


Figure 11-11 Non-Overlapping Operation and NDR Write Timing

Section 12 8-Bit Timers

12.1 Overview

The H8S/2357 Series includes an 8-bit timer module with two channels (TMR0 and TMR1). Each channel has an 8-bit counter (TCNT) and two time constant registers (TCORA and TCORB) that are constantly compared with the TCNT value to detect compare match events. The 8-bit timer module can thus be used for a variety of functions, including pulse output with an arbitrary duty cycle.

12.1.1 Features

The features of the 8-bit timer module are listed below.

- Selection of four clock sources
 - The counters can be driven by one of three internal clock signals ($\emptyset/8$, $\emptyset/64$, or $\emptyset/8192$) or an external clock input (enabling use as an external event counter).
- Selection of three ways to clear the counters
 The counters can be cleared on compare match A or B, or by an external reset signal.
- Timer output control by a combination of two compare match signals
 The timer output signal in each channel is controlled by a combination of two independent compare match signals, enabling the timer to generate output waveforms with an arbitrary duty cycle or PWM output.
- Provision for cascading of two channels
 - Operation as a 16-bit timer is possible, using channel 0 for the upper 8 bits and channel 1 for the lower 8 bits (16-bit count mode).
 - Channel 1 can be used to count channel 0 compare matches (compare match count mode).
- Three independent interrupts
 - Compare match A and B and overflow interrupts can be requested independently.
- A/D converter conversion start trigger can be generated

 Channel 0 compare match A signal can be used as an A/D converter conversion start trigger.
- Module stop mode can be set
 - As the initial setting, 8-bit timer operation is halted. Register access is enabled by exiting module stop mode.

12.1.2 Block Diagram

Figure 12-1 shows a block diagram of the 8-bit timer module.

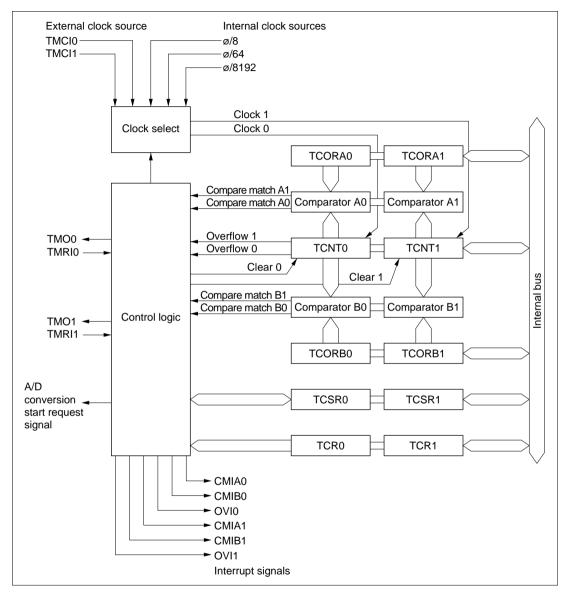


Figure 12-1 Block Diagram of 8-Bit Timer

12.1.3 Pin Configuration

Table 12-1 summarizes the input and output pins of the 8-bit timer.

Table 12-1 Input and Output Pins of 8-Bit Timer

Channel	Name	Symbol	I/O	Function
0	Timer output pin 0	TMO0	Output	Outputs at compare match
	Timer clock input pin 0	TMCI0	Input	Inputs external clock for counter
	Timer reset input pin 0	TMRI0	Input	Inputs external reset to counter
1	Timer output pin 1	TMO1	Output	Outputs at compare match
	Timer clock input pin 1	TMCI1	Input	Inputs external clock for counter
	Timer reset input pin 1	TMRI1	Input	Inputs external reset to counter

12.1.4 Register Configuration

Table 12-2 summarizes the registers of the 8-bit timer module.

Table 12-2 8-Bit Timer Registers

Channel	Name	Abbreviation	R/W	Initial value	Address*1
0	Timer control register 0	TCR0	R/W	H'00	H'FFB0
	Timer control/status register 0	TCSR0	R/(W)*2	H'00	H'FFB2
	Time constant register A0	TCORA0	R/W	H'FF	H'FFB4
	Time constant register B0	TCORB0	R/W	H'FF	H'FFB6
	Timer counter 0	TCNT0	R/W	H'00	H'FFB8
1	Timer control register 1	TCR1	R/W	H'00	H'FFB1
	Timer control/status register 1	TCSR1	R/(W)*2	H'10	H'FFB3
	Time constant register A1	TCORA1	R/W	H'FF	H'FFB5
	Time constant register B1	TCORB1	R/W	H'FF	H'FFB7
	Timer counter 1	TCNT1	R/W	H'00	H'FFB9
All	Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address

2. Only 0 can be written to bits 7 to 5, to clear these flags.

Each pair of registers for channel 0 and channel 1 is a 16-bit register with the upper 8 bits for channel 0 and the lower 8 bits for channel 1, so they can be accessed together by word transfer instruction.

12.2 Register Descriptions

12.2.1 Timer Counters 0 and 1 (TCNT0, TCNT1)

		TCNT0									TCI	NT1				
Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial value:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

TCNT0 and TCNT1 are 8-bit readable/writable up-counters that increment on pulses generated from an internal or external clock source. This clock source is selected by clock select bits CKS2 to CKS0 of TCR. The CPU can read or write to TCNT0 and TCNT1 at all times.

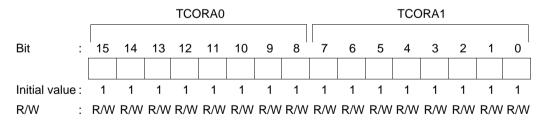
TCNT0 and TCNT1 comprise a single 16-bit register, so they can be accessed together by word transfer instruction.

TCNT0 and TCNT1 can be cleared by an external reset input or by a compare match signal. Which signal is to be used for clearing is selected by clock clear bits CCLR1 and CCLR0 of TCR.

When a timer counter overflows from H'FF to H'00, OVF in TCSR is set to 1.

TCNT0 and TCNT1 are each initialized to H'00 by a reset and in hardware standby mode.

12.2.2 Time Constant Registers A0 and A1 (TCORA0, TCORA1)



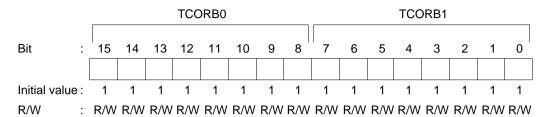
TCORA0 and TCORA1 are 8-bit readable/writable registers. TCORA0 and TCORA1 comprise a single 16-bit register so they can be accessed together by word transfer instruction.

TCORA is continually compared with the value in TCNT. When a match is detected, the corresponding CMFA flag of TCSR is set. Note, however, that comparison is disabled during the T2 state of a TCOR write cycle.

The timer output can be freely controlled by these compare match signals and the settings of bits OS1 and OS0 of TCSR.

TCORA0 and TCORA1 are each initialized to H'FF by a reset and in hardware standby mode.

12.2.3 Time Constant Registers B0 and B1 (TCORB0, TCORB1)



TCORB0 and TCORB1 are 8-bit readable/writable registers. TCORB0 and TCORB1 comprise a single 16-bit register so they can be accessed together by word transfer instruction.

TCORB is continually compared with the value in TCNT. When a match is detected, the corresponding CMFB flag of TCSR is set. Note, however, that comparison is disabled during the T2 state of a TCOR write cycle.

The timer output can be freely controlled by these compare match signals and the settings of output select bits OS3 and OS2 of TCSR.

TCORB0 and TCORB1 are each initialized to H'FF by a reset and in hardware standby mode.

12.2.4 Time Control Registers 0 and 1 (TCR0, TCR1)

Bit	Bit :		6	5	4	3	2	1	0
		CMIEB	CMIEA	OVIE	CCLR1	CCLR0	CKS2	CKS1	CKS0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

TCR0 and TCR1 are 8-bit readable/writable registers that select the clock source and the time at which TCNT is cleared, and enable interrupts.

TCR0 and TCR1 are each initialized to H'00 by a reset and in hardware standby mode.

For details of this timing, see section 12.3, Operation.

Bit 7—Compare Match Interrupt Enable B (CMIEB): Selects whether CMFB interrupt requests (CMIB) are enabled or disabled when the CMFB flag of TCSR is set to 1.

Bit 7 CMIEB	Description	
0	CMFB interrupt requests (CMIB) are disabled	(Initial value)
1	CMFB interrupt requests (CMIB) are enabled	

Bit 6—Compare Match Interrupt Enable A (CMIEA): Selects whether CMFA interrupt requests (CMIA) are enabled or disabled when the CMFA flag of TCSR is set to 1.

Bit 6 CMIEA	Description	
0	CMFA interrupt requests (CMIA) are disabled	(Initial value)
1	CMFA interrupt requests (CMIA) are enabled	

Bit 5—Timer Overflow Interrupt Enable (OVIE): Selects whether OVF interrupt requests (OVI) are enabled or disabled when the OVF flag of TCSR is set to 1.

Bit 5 OVIE	Description	
0	OVF interrupt requests (OVI) are disabled	(Initial value)
1	OVF interrupt requests (OVI) are enabled	

Bits 4 and 3—Counter Clear 1 and 0 (CCLR1 and CCLR0): These bits select the method by which TCNT is cleared: by compare match A or B, or by an external reset input.

Bit 4 CCLR1	Bit 3 CCLR0	Description	
0	0	Clear is disabled	(Initial value)
	1	Clear by compare match A	
1	0	Clear by compare match B	
	1	Clear by rising edge of external reset input	

Bits 2 to 0—Clock Select 2 to 0 (CKS2 to CKS0): These bits select whether the clock input to TCNT is an internal or external clock.

Three internal clocks can be selected, all divided from the system clock (\emptyset): $\emptyset/8$, $\emptyset/64$, and $\emptyset/8192$. The falling edge of the selected internal clock triggers the count.

When use of an external clock is selected, three types of count can be selected: at the rising edge, the falling edge, and both rising and falling edges.

Some functions differ between channel 0 and channel 1.

Bit 2 CKS2	Bit 1 CKS1	Bit 0 CKS0	Description	
0	0	0	Clock input disabled	(Initial value)
		1	Internal clock, counted at falling edge of ø/8	
	1	0	Internal clock, counted at falling edge of ø/64	
		1	Internal clock, counted at falling edge of ø/8192	
1	0	0	For channel 0: count at TCNT1 overflow signal*	
			For channel 1: count at TCNT0 compare match A*	
		1	External clock, counted at rising edge	
	1	0	External clock, counted at falling edge	
		1	External clock, counted at both rising and falling edges	S

Note: * If the count input of channel 0 is the TCNT1 overflow signal and that of channel 1 is the TCNT0 compare match signal, no incrementing clock is generated. Do not use this setting.

12.2.5 Timer Control/Status Registers 0 and 1 (TCSR0, TCSR1)

TCSR0

Bit	:	7	6	5	4	3	2	1	0
	•	CMFB	CMFA	OVF	ADTE	OS3	OS2	OS1	OS0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/(W)*	R/(W)*	R/(W)*	R/W	R/W	R/W	R/W	R/W
TCSR1									
Bit	:	7	6	5	4	3	2	1	0

DIL .	,	O	5	4	3	2	1	U	
	CMFB	CMFA	OVF	_	OS3	OS2	OS1	OS0	I
Initial value:	0	0	0	1	0	0	0	0	
R/W :	R/(W)*	R/(W)*	R/(W)*	_	R/W	R/W	R/W	R/W	

Note: * Only 0 can be written to bits 7 to 5, to clear these flags.

TCSR0 and TCSR1 are 8-bit registers that display compare match and overflow statuses, and control compare match output.

TCSR0 is initialized to H'00, and TCSR1 to H'10, by a reset and in hardware standby mode.

Bit 7—Compare Match Flag B (CMFB): Status flag indicating whether the values of TCNT and TCORB match.

Bit 7 CMFB	Description
0	[Clearing conditions] (Initial value)
	 Cleared by reading CMFB when CMFB = 1, then writing 0 to CMFB
	 When DTC is activated by CMIB interrupt while DISEL bit of MRB in DTC is 0
1	[Setting condition]
	Set when TCNT matches TCORB

Bit 6—Compare Match Flag A (CMFA): Status flag indicating whether the values of TCNT and TCORA match.

Bit 6 CMFA	Description	
0	[Clearing conditions] (Initial value	e)
	 Cleared by reading CMFA when CMFA = 1, then writing 0 to CMFA 	
	 When DTC is activated by CMIA interrupt while DISEL bit of MRB in DTC is 0 	
1	[Setting condition]	
	Set when TCNT matches TCORA	

Bit 5—Timer Overflow Flag (OVF): Status flag indicating that TCNT has overflowed (changed from H'FF to H'00).

Bit 5 OVF	Description	
0	[Clearing condition]	(Initial value)
	 Cleared by reading OVF when OVF = 1, then writing 0 to OVF 	
1	[Setting condition]	
	Set when TCNT overflows from H'FF to H'00	

Bit 4—A/D Trigger Enable (ADTE) (TCSR0 Only): Selects enabling or disabling of A/D converter start requests by compare-match A.

In TCSR1, this bit is reserved: it is always read as 1 and cannot be modified.

Bit 4		
ADTE	Description	
0	A/D converter start requests by compare match A are disabled	(Initial value)
1	A/D converter start requests by compare match A are enabled	

Bits 3 to 0—Output Select 3 to 0 (OS3 to OS0): These bits specify how the timer output level is to be changed by a compare match of TCOR and TCNT.

Bits OS3 and OS2 select the effect of compare match B on the output level, bits OS1 and OS0 select the effect of compare match A on the output level, and both of them can be controlled independently.

Note, however, that priorities are set such that: toggle output > 1 output > 0 output. If compare matches occur simultaneously, the output changes according to the compare match with the higher priority.

Timer output is disabled when bits OS3 to OS0 are all 0.

After a reset, the timer output is 0 until the first compare match event occurs.

Bit 2 OS2	Description	
0	No change when compare match B occurs	(Initial value)
1	0 is output when compare match B occurs	
0	1 is output when compare match B occurs	
1	Output is inverted when compare match B occurs (toggle output)	
	0 1	OS2 Description O No change when compare match B occurs O is output when compare match B occurs O 1 is output when compare match B occurs

Bit 0 OS0	Description	
0	No change when compare match A occurs	(Initial value)
1	0 is output when compare match A occurs	
0	1 is output when compare match A occurs	
1	Output is inverted when compare match A occurs (toggle output)	
	0 1	OS0 Description O No change when compare match A occurs O is output when compare match A occurs O 1 is output when compare match A occurs

12.2.6 Module Stop Control Register (MSTPCR)

		MSTPCRH							MSTPCRL							
Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial value:	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	1
R/W :	R/W	/ R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP12 bit in MSTPCR is set to 1, the 8-bit timer operation stops at the end of the bus cycle and a transition is made to module stop mode. Registers cannot be read or written to in module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 12—Module Stop (MSTP12): Specifies the 8-bit timer stop mode.

Bit 12 MSTP12

MSTP12	Description
	Description

0	8-bit timer module stop mode cleared	
1	8-bit timer module stop mode set	(Initial value)

12.3 Operation

12.3.1 TCNT Incrementation Timing

TCNT is incremented by input clock pulses (either internal or external).

Internal Clock: Three different internal clock signals ($\emptyset/8$, $\emptyset/64$, or $\emptyset/8192$) divided from the system clock (\emptyset) can be selected, by setting bits CKS2 to CKS0 in TCR. Figure 12-2 shows the count timing.

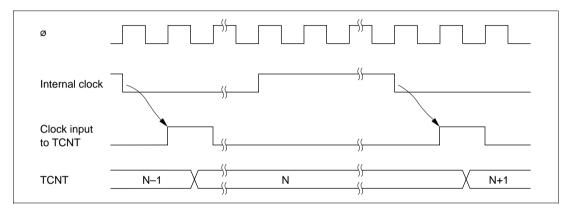


Figure 12-2 Count Timing for Internal Clock Input

External Clock: Three incrementation methods can be selected by setting bits CKS2 to CKS0 in TCR: at the rising edge, the falling edge, and both rising and falling edges.

Note that the external clock pulse width must be at least 1.5 states for incrementation at a single edge, and at least 2.5 states for incrementation at both edges. The counter will not increment correctly if the pulse width is less than these values.

Figure 12-3 shows the timing of incrementation at both edges of an external clock signal.

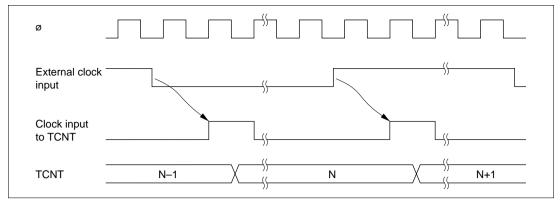


Figure 12-3 Count Timing for External Clock Input

12.3.2 Compare Match Timing

Setting of Compare Match Flags A and B (CMFA, CMFB): The CMFA and CMFB flags in TCSR are set to 1 by a compare match signal generated when the TCOR and TCNT values match. The compare match signal is generated at the last state in which the match is true, just before the timer counter is updated.

Therefore, when TCOR and TCNT match, the compare match signal is not generated until the next incrementation clock input. Figure 12-4 shows this timing.

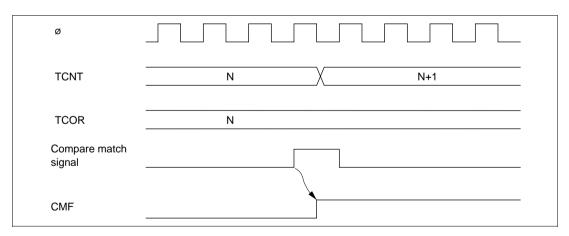


Figure 12-4 Timing of CMF Setting

Timer Output Timing: When compare match A or B occurs, the timer output changes a specified by bits OS3 to OS0 in TCSR. Depending on these bits, the output can remain the same, change to 0, change to 1, or toggle.

Figure 12-5 shows the timing when the output is set to toggle at compare match A.

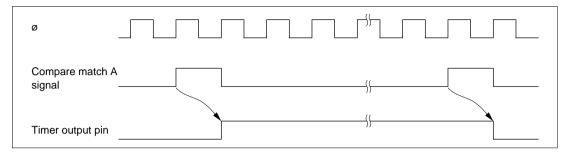


Figure 12-5 Timing of Timer Output

Timing of Compare Match Clear: The timer counter is cleared when compare match A or B occurs, depending on the setting of the CCLR1 and CCLR0 bits in TCR. Figure 12-6 shows the timing of this operation.

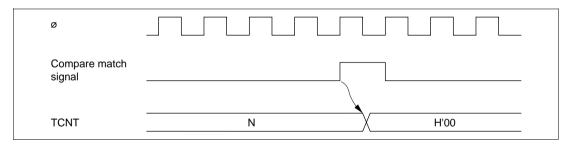


Figure 12-6 Timing of Compare Match Clear

12.3.3 Timing of External RESET on TCNT

TCNT is cleared at the rising edge of an external reset input, depending on the settings of the CCLR1 and CCLR0 bits in TCR. The clear pulse width must be at least 1.5 states. Figure 12-7 shows the timing of this operation.

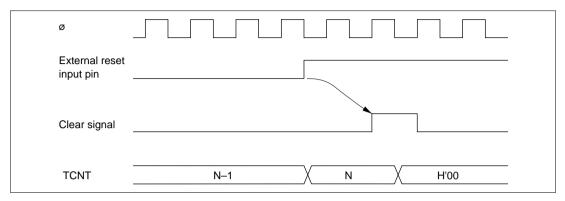


Figure 12-7 Timing of External Reset

12.3.4 Timing of Overflow Flag (OVF) Setting

The OVF in TCSR is set to 1 when the timer count overflows (changes from H'FF to H'00). Figure 12-8 shows the timing of this operation.

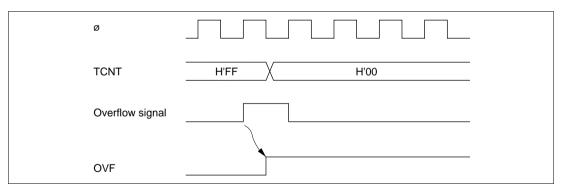


Figure 12-8 Timing of OVF Setting

12.3.5 Operation with Cascaded Connection

If bits CKS2 to CKS0 in either TCR0 or TCR1 are set to B'100, the 8-bit timers of the two channels are cascaded. With this configuration, a single 16-bit timer could be used (16-bit timer mode) or compare matches of the 8-bit channel 0 could be counted by the timer of channel 1 (compare match counter mode). In this case, the timer operates as below.

16-Bit Counter Mode: When bits CKS2 to CKS0 in TCR0 are set to B'100, the timer functions as a single 16-bit timer with channel 0 occupying the upper 8 bits and channel 1 occupying the lower 8 bits.

- Setting of compare match flags
 - The CMF flag in TCSR0 is set to 1 when a 16-bit compare match event occurs.
 - The CMF flag in TCSR1 is set to 1 when a lower 8-bit compare match event occurs.
- Counter clear specification
 - If the CCLR1 and CCLR0 bits in TCR0 have been set for counter clear at compare match, the 16-bit counter (TCNT0 and TCNT1 together) is cleared when a 16-bit compare match event occurs. The 16-bit counter (TCNT0 and TCNT1 together) is cleared even if counter clear by the TMRI0 pin has also been set.
 - The settings of the CCLR1 and CCLR0 bits in TCR1 are ignored. The lower 8 bits cannot be cleared independently.

Pin output

- Control of output from the TMO0 pin by bits OS3 to OS0 in TCSR0 is in accordance with the 16-bit compare match conditions.
- Control of output from the TMO1 pin by bits OS3 to OS0 in TCSR1 is in accordance with the lower 8-bit compare match conditions.

Compare Match Counter Mode: When bits CKS2 to CKS0 in TCR1 are B'100, TCNT1 counts compare match A's for channel 0.

Channels 0 and 1 are controlled independently. Conditions such as setting of the CMF flag, generation of interrupts, output from the TMO pin, and counter clear are in accordance with the settings for each channel.

Note on Usage: If the 16-bit counter mode and compare match counter mode are set simultaneously, the input clock pulses for TCNT0 and TCNT1 are not generated and thus the counters will stop operating. Software should therefore avoid using both these modes.

12.4 Interrupts

12.4.1 Interrupt Sources and DTC Activation

There are three 8-bit timer interrupt sources: CMIA, CMIB, and OVI. Their relative priorities are shown in Table 12-3. Each interrupt source is set as enabled or disabled by the corresponding interrupt enable bit in TCR, and independent interrupt requests are sent for each to the interrupt controller. It is also possible to activate the DTC by means of CMIA and CMIB interrupts.

Table 12-3 8-Bit Timer Interrupt Sources

Interrupt Source	Description	DTC Activation	Priority		
CMIA0	Interrupt by CMFA	Possible	High		
CMIB0	Interrupt by CMFB	Possible			
OVI0	Interrupt by OVF	Not possible			
CMIA1	Interrupt by CMFA Possible				
CMIB1	Interrupt by CMFB	Possible			
OVI1	Interrupt by OVF	Not possible	Low		

Note: This table shows the initial state immediately after a reset. The relative channel priorities can be changed by the interrupt controller.

12.4.2 A/D Converter Activation

The A/D converter can be activated only by channel 0 compare match A.

If the ADTE bit in TCSR0 is set to 1 when the CMFA flag is set to 1 by the occurrence of channel 0 compare match A, a request to start A/D conversion is sent to the A/D converter. If the 8-bit timer conversion start trigger has been selected on the A/D converter side at this time, A/D conversion is started.

12.5 Sample Application

In the example below, the 8-bit timer is used to generate a pulse output with a selected duty cycle, as shown in figure 12-9. The control bits are set as follows:

- [1] In TCR, bit CCLR1 is cleared to 0 and bit CCLR0 is set to 1 so that the timer counter is cleared when its value matches the constant in TCORA.
- [2] In TCSR, bits OS3 to OS0 are set to B'0110, causing the output to change to 1 at a TCORA compare match and to 0 at a TCORB compare match.

With these settings, the 8-bit timer provides output of pulses at a rate determined by TCORA with a pulse width determined by TCORB. No software intervention is required.

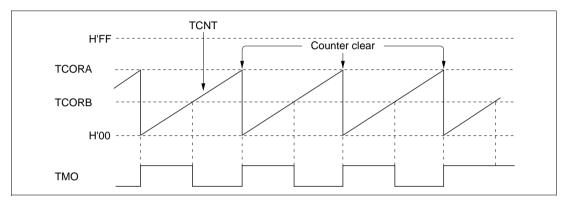


Figure 12-9 Example of Pulse Output

12.6 Usage Notes

Application programmers should note that the following kinds of contention can occur in the 8-bit timer.

12.6.1 Contention between TCNT Write and Clear

If a timer counter clock pulse is generated during the T_2 state of a TCNT write cycle, the clear takes priority, so that the counter is cleared and the write is not performed.

Figure 12-10 shows this operation.

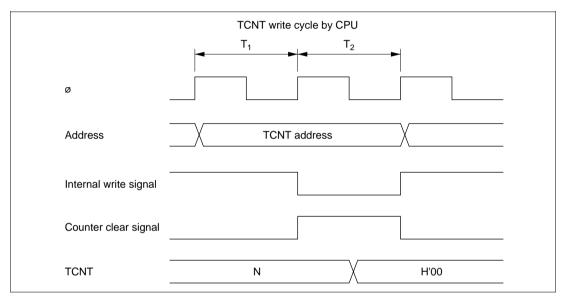


Figure 12-10 Contention between TCNT Write and Clear

12.6.2 Contention between TCNT Write and Increment

If a timer counter clock pulse is generated during the T_2 state of a TCNT write cycle, the write takes priority and the counter is not incremented.

Figure 12-11 shows this operation.

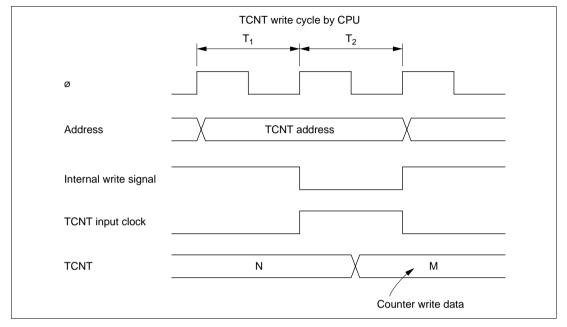


Figure 12-11 Contention between TCNT Write and Increment

12.6.3 Contention between TCOR Write and Compare Match

During the T₂ state of a TCOR write cycle, the TCOR write has priority and the compare match signal is disabled even if a compare match event occurs.

Figure 12-12 shows this operation.

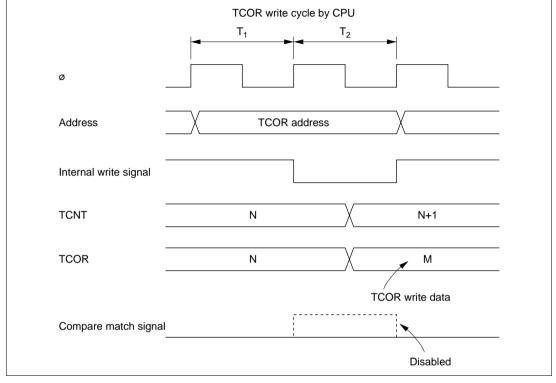


Figure 12-12 Contention between TCOR Write and Compare Match

12.6.4 Contention between Compare Matches A and B

If compare match events A and B occur at the same time, the 8-bit timer operates in accordance with the priorities for the output statuses set for compare match A and compare match B, as shown in table 12-4.

Table 12-4 Timer Output Priorities

Output Setting	Priority
Toggle output	High
1 output	
0 output	
No change	Low

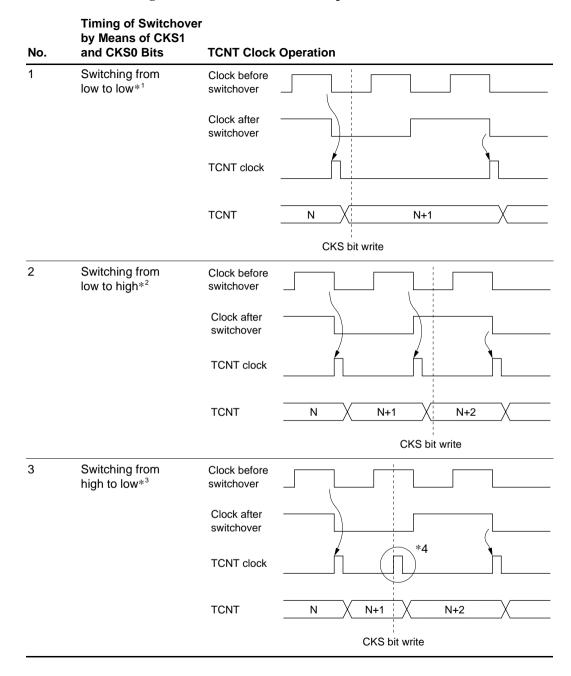
12.6.5 Switching of Internal Clocks and TCNT Operation

TCNT may increment erroneously when the internal clock is switched over. Table 12-5 shows the relationship between the timing at which the internal clock is switched (by writing to the CKS1 and CKS0 bits) and the TCNT operation.

When the TCNT clock is generated from an internal clock, the falling edge of the internal clock pulse is detected. If clock switching causes a change from high to low level, as shown in case 3 in table 12-5, a TCNT clock pulse is generated on the assumption that the switchover is a falling edge. This increments TCNT.

The erroneous incrementation can also happen when switching between internal and external clocks.

Table 12-5 Switching of Internal Clock and TCNT Operation



by Means of CKS1 No. and CKS0 Bits **TCNT Clock Operation** 4 Clock before Switching from high switchover to high Clock after switchover TCNT clock **TCNT** Ν N+1 N+2 CKS bit write

Notes: 1. Includes switching from low to stop, and from stop to low.

2. Includes switching from stop to high.

Timing of Switchover

- 3. Includes switching from high to stop.
- Generated on the assumption that the switchover is a falling edge; TCNT is incremented.

12.6.6 Usage Note

Interrupts and Module Stop Mode: If module stop mode is entered when an interrupt has been requested, it will not be possible to clear the CPU interrupt source or the DMAC or DTC activation source. Interrupts should therefore be disabled before entering module stop mode.

Section 13 Watchdog Timer

13.1 Overview

The H8S/2357 Series has a single-channel on-chip watchdog timer (WDT) for monitoring system operation. The WDT outputs an overflow signal (WDTOVF) if a system crash prevents the CPU from writing to the timer counter, allowing it to overflow. At the same time, the WDT can also generate an internal reset signal for the H8S/2357 Series.

When this watchdog function is not needed, the WDT can be used as an interval timer. In interval timer operation, an interval timer interrupt is generated each time the counter overflows.

13.1.1 Features

WDT features are listed below.

- Switchable between watchdog timer mode and interval timer mode
- WDTOVF output when in watchdog timer mode*¹
 If the counter overflows, the WDT outputs WDTOVF. It is possible to select whether or not the entire H8S/2357 Series is reset at the same time. This internal reset can be a power-on reset or a manual reset.*²
- Interrupt generation when in interval timer mode
 If the counter overflows, the WDT generates an interval timer interrupt.
- Choice of eight counter clock sources.
- Notes: 1. The WDTOVF pin function is not available in the F-ZTAT versions, and the H8S/2398, H8S/2394, H8S/2392, and H8S/2390.
 - 2. Manual reset is only supported in the H8S/2357 ZTAT version.

13.1.2 Block Diagram

Figure 13-1 shows a block diagram of the WDT.

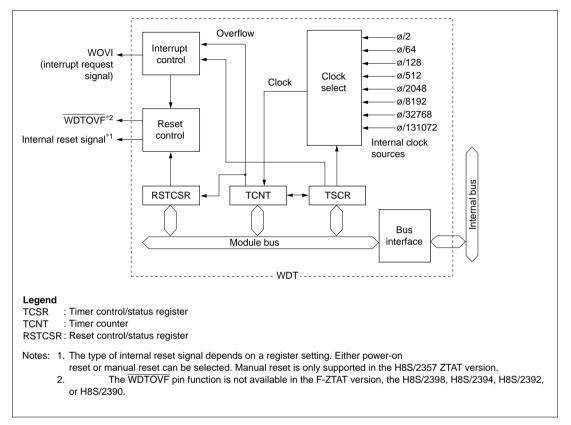


Figure 13-1 Block Diagram of WDT

13.1.3 Pin Configuration

Table 13-1 describes the WDT output pin.

Table 13-1 WDT Pin

Name	Symbol	I/O	Function
Watchdog timer overflow	WDTOVF*	Output	Outputs counter overflow signal in watchdog timer mode

Note: * The WDTOVF pin function is not available in the F-ZTAT version, the H8S/2398, H8S/2394, H8S/2392 or H8S/2390.

13.1.4 Register Configuration

The WDT has three registers, as summarized in table 13-2. These registers control clock selection, WDT mode switching, and the reset signal.

Table 13-2 WDT Registers

				Add	ress*1
Name	Abbreviation	R/W	Initial Value	Write*2	Read
Timer control/status register	TCSR	R/(W)*3	H'18	H'FFBC	H'FFBC
Timer counter	TCNT	R/W	H'00	H'FFBC	H'FFBD
Reset control/status register	RSTCSR	R/(W)*3	H'1F	H'FFBE	H'FFBF

Notes: 1. Lower 16 bits of the address.

- 2. For details of write operations, see section 13.2.4, Notes on Register Access.
- 3. Only a write of 0 is permitted to bit 7, to clear the flag.

13.2 Register Descriptions

13.2.1 Timer Counter (TCNT)

Bit	:	7	6	5	4	3	2	1	0
Initial va	ılue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

TCNT is an 8-bit readable/writable*1 up-counter.

When the TME bit is set to 1 in TCSR, TCNT starts counting pulses generated from the internal clock source selected by bits CKS2 to CKS0 in TCSR. When the count overflows (changes from H'FF to H'00), either the watchdog timer overflow signal (WDTOVF)*2 or an interval timer interrupt (WOVI) is generated, depending on the mode selected by the WT/IT bit in TCSR.

TCNT is initialized to H'00 by a reset, in hardware standby mode, or when the TME bit is cleared to 0. It is not initialized in software standby mode.

Notes: 1. TCNT is write-protected by a password to prevent accidental overwriting. For details see section 13.2.4, Notes on Register Access.

2. The WDTOVF pin function is not available in the F-ZTAT version, the H8S/2398, H8S/2394. H8S/2392 or H8S/2390.

13.2.2 Timer Control/Status Register (TCSR)

Bit	:	7	6	5	4	3	2	1	0
		OVF	WT/ IT	TME	_		CKS2	CKS1	CKS0
Initial va	alue :	0	0	0	1	1	0	0	0
R/W	:	R/(W)*	R/W	R/W	_	_	R/W	R/W	R/W

Note: * Can only be written with 0 for flag clearing.

TCSR is an 8-bit readable/writable* register. Its functions include selecting the clock source to be input to TCNT, and the timer mode.

TCR is initialized to H'18 by a reset and in hardware standby mode. It is not initialized in software standby mode.

Note: * TCSR is write-protected by a password to prevent accidental overwriting. For details see section 13.2.4, Notes on Register Access.

Bit 7—Overflow Flag (OVF): Indicates that TCNT has overflowed from H'FF to H'00, when in interval timer mode. This flag cannot be set during watchdog timer operation.

Bit 7 OVF	Description				
0	[Clearing condition]				
	Cleared by reading TCSR when OVF = 1, then writing 0 to OVF	(Initial value)			
1	[Setting condition]				
	Set when TCNT overflows (changes from H'FF to H'00) in interval timer mode				

Bit 6—Timer Mode Select (WT/IT): Selects whether the WDT is used as a watchdog timer or interval timer. If used as an interval timer, the WDT generates an interval timer interrupt request (WOVI) when TCNT overflows. If used as a watchdog timer, the WDT generates the WDTOVF signal*1 when TCNT overflows.

Bit 6 WT/IT	Description
0	Interval timer: Sends the CPU an interval timer interrupt request (WOVI) when TCNT overflows (Initial value
1	Watchdog timer: Generates the WDTOVF signal*1 when TCNT overflows*2
Notes: 1	I. The WDTOVF pin function is not available in the F-ZTAT version, the H8S/2398, H8S/2394, H8S/2392 or H8S/2390.
2	2. For details of the case where TCNT overflows in watchdog timer mode, see section 13.2.3, Reset Control/Status Register (RSTCSR).

Bit 5—Timer Enable (TME): Selects whether TCNT runs or is halted.

Bit 5		
TME	Description	
0	TCNT is initialized to H'00 and halted	(Initial value)
1	TCNT counts	

Bits 4 and 3—Reserved: These bits cannot be modified and are always read as 1.

Bits 2 to 0: Clock Select 2 to 0 (CKS2 to CKS0): These bits select one of eight internal clock sources, obtained by dividing the system clock (ø), for input to TCNT.

			Description		
Bit 2 CKS2	Bit 1 CKS1	Bit 0 CKS0	Clock	Overflow Period (when ø = 20 MHz)*	
0	0	0	ø/2 (initial value)	25.6 µs	
		1	ø/64	819.2 µs	
	1	0	ø/128	1.6 ms	
		1	ø/512	6.6 ms	
1	0	0	ø/2048	26.2 ms	
		1	ø/8192	104.9 ms	
	1	0	ø/32768	419.4 ms	
		1	ø/131072	1.68 s	

Note: *The overflow period is the time from when TCNT starts counting up from H'00 until overflow occurs.

13.2.3 Reset Control/Status Register (RSTCSR)

Bit	:	7	6	5	4	3	2	1	0
		WOVF	RSTE	RSTS	_	_	_	_	_
Initial va	alue :	0	0	0	1	1	1	1	1
R/W	:	R/(W)*	R/W	R/W	_	_	_	_	_

Note: * Can only be written with 0 for flag clearing.

RSTCSR is an 8-bit readable/writable* register that controls the generation of the internal reset signal when TCNT overflows, and selects the type of internal reset signal.

RSTCSR is initialized to H'1F by a reset signal from the \overline{RES} pin, but not by the WDT internal reset signal caused by overflows.

Note: * RSTCSR is write-protected by a password to prevent accidental overwriting. For details see section 13.2.4, Notes on Register Access.

Bit 7—Watchdog Overflow Flag (WOVF): Indicates that TCNT has overflowed (changed from H'FF to H'00) during watchdog timer operation. This bit is not set in interval timer mode.

Bit 7 WOVF	Description				
0	[Clearing condition]	(Initial value)			
	Cleared by reading TCSR when WOVF = 1, then writing 0 to WOVF				
1	[Setting condition]				
	Set when TCNT overflows (changed from H'FF to H'00) during watchdog timer operation				

Bit 6—Reset Enable (RSTE): Specifies whether or not a reset signal is generated in the H8S/2357 Series if TCNT overflows during watchdog timer operation.

Bit 6 RSTE	Description	
0	Reset signal is not generated if TCNT overflows*	(Initial value)
1	Reset signal is generated if TCNT overflows	

Note: * The modules within the H8S/2357 Series are not reset, but TCNT and TCSR within the WDT are reset.

Bit 5—Reset Select (RSTS): Selects the type of internal reset generated if TCNT overflows during watchdog timer operation.

For details of the types of resets, see section 4, Exception Handling.

Bit 5 RSTS	Description	
0	Power-on reset	(Initial value)
1	Manual reset*	

Note: * Manual reset is supported only in the H8S/2357 ZTAT version. In the models except the H8S/2357 ZTAT version, only 0 should be written to this bit.

Bits 4 to 0—Reserved: These bits cannot be modified and are always read as 1.

13.2.4 Notes on Register Access

The watchdog timer's TCNT, TCSR, and RSTCSR registers differ from other registers in being more difficult to write to. The procedures for writing to and reading these registers are given below.

Writing to TCNT and TCSR: These registers must be written to by a word transfer instruction. They cannot be written to with byte instructions.

Figure 13-2 shows the format of data written to TCNT and TCSR. TCNT and TCSR both have the same write address. For a write to TCNT, the upper byte of the written word must contain H'5A and the lower byte must contain the write data. For a write to TCSR, the upper byte of the written word must contain H'A5 and the lower byte must contain the write data. This transfers the write data from the lower byte to TCNT or TCSR.

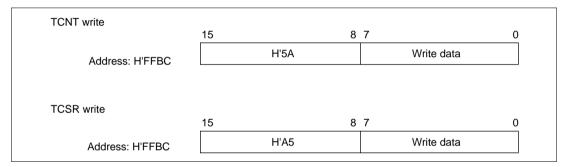


Figure 13-2 Format of Data Written to TCNT and TCSR

Writing to RSTCSR: RSTCSR must be written to by word transfer instruction to address H'FFBE. It cannot be written to with byte instructions.

Figure 13-3 shows the format of data written to RSTCSR. The method of writing 0 to the WOVF bit differs from that for writing to the RSTE and RSTS bits.

To write 0 to the WOVF bit, the write data must have H'A5 in the upper byte and H'00 in the lower byte. This clears the WOVF bit to 0, but has no effect on the RSTE and RSTS bits. To write to the RSTE and RSTS bits, the upper byte must contain H'5A and the lower byte must contain the write data. This writes the values in bits 6 and 5 of the lower byte into the RSTE and RSTS bits, but has no effect on the WOVF bit.

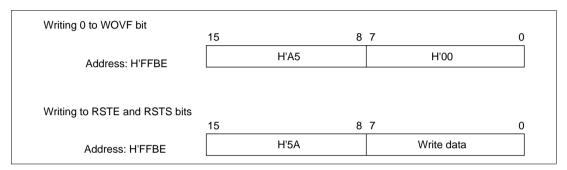


Figure 13-3 Format of Data Written to RSTCSR

Reading TCNT, TCSR, and RSTCSR: These registers are read in the same way as other registers. The read addresses are H'FFBC for TCSR, H'FFBD for TCNT, and H'FFBF for RSTCSR.

13.3 Operation

13.3.1 Watchdog Timer Operation

To use the WDT as a watchdog timer, set the WT/ $\overline{\text{IT}}$ and TME bits to 1. Software must prevent TCNT overflows by rewriting the TCNT value (normally be writing H'00) before overflows occurs. This ensures that TCNT does not overflow while the system is operating normally. If TCNT overflows without being rewritten because of a system crash or other error, the $\overline{\text{WDTOVF}}$ signal*¹ is output. This is shown in figure 13-4. This $\overline{\text{WDTOVF}}$ signal*¹ can be used to reset the system. The $\overline{\text{WDTOVF}}$ signal*¹ is output for 132 states when RSTE = 1, and for 130 states when RSTE = 0.

If TCNT overflows when 1 is set in the RSTE bit in RSTCSR, a signal that resets the H8S/2357 Series internally is generated at the same time as the WDTOVF signal*¹. This reset can be selected as a power-on reset or a manual reset*², depending on the setting of the RSTS bit in RSTCSR. The internal reset signal is output for 518 states.

If a reset caused by a signal input to the \overline{RES} pin occurs at the same time as a reset caused by a WDT overflow, the \overline{RES} pin reset has priority and the WOVF bit in RSTCSR is cleared to 0.

Notes: 1. In the F-ZTAT version, the H8S/2398, H8S/2394, H8S/2392, or H8S/2390, the WDTOVF pin function is not available.

2. Manual reset is only supported in the H8S/2357 ZTAT version.

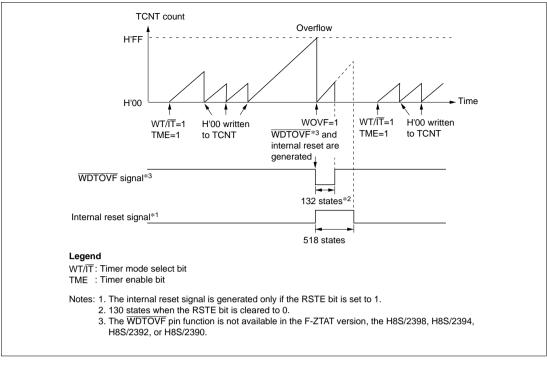


Figure 13-4 Watchdog Timer Operation

13.3.2 Interval Timer Operation

To use the WDT as an interval timer, clear the WT/TT bit in TCSR to 0 and set the TME bit to 1. An interval timer interrupt (WOVI) is generated each time TCNT overflows, provided that the WDT is operating as an interval timer, as shown in figure 13-5. This function can be used to generate interrupt requests at regular intervals.

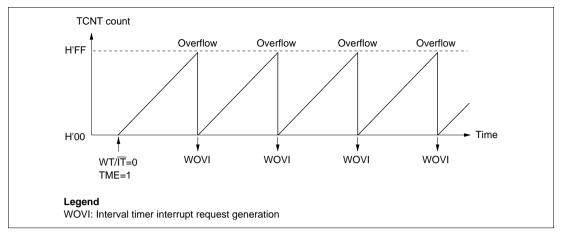


Figure 13-5 Interval Timer Operation

13.3.3 Timing of Setting Overflow Flag (OVF)

The OVF flag is set to 1 if TCNT overflows during interval timer operation. At the same time, an interval timer interrupt (WOVI) is requested. This timing is shown in figure 13-6.

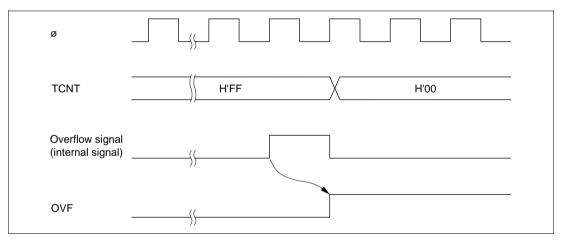


Figure 13-6 Timing of Setting of OVF

13.3.4 Timing of Setting of Watchdog Timer Overflow Flag (WOVF)

The WOVF flag is set to 1 if TCNT overflows during watchdog timer operation. At the same time, the WDTOVF signal* goes low. If TCNT overflows while the RSTE bit in RSTCSR is set to 1, an internal reset signal is generated for the entire H8S/2357 Series chip. Figure 13-7 shows the timing in this case.

Note: * The WDTOVF pin function is not available in the F-ZTAT version, the H8S/2394, H8S/2392, or H8S/2390.

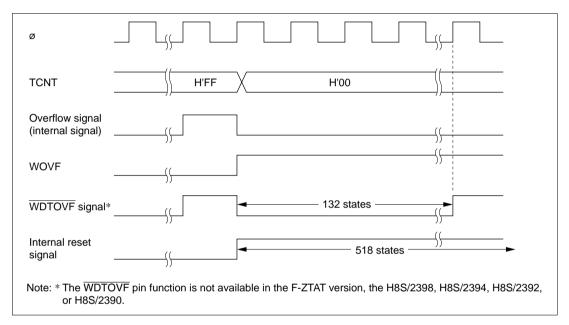


Figure 13-7 Timing of Setting of WOVF

13.4 Interrupts

During interval timer mode operation, an overflow generates an interval timer interrupt (WOVI). The interval timer interrupt is requested whenever the OVF flag is set to 1 in TCSR.

13.5 Usage Notes

13.5.1 Contention between Timer Counter (TCNT) Write and Increment

If a timer counter clock pulse is generated during the T_2 state of a TCNT write cycle, the write takes priority and the timer counter is not incremented. Figure 13-8 shows this operation.

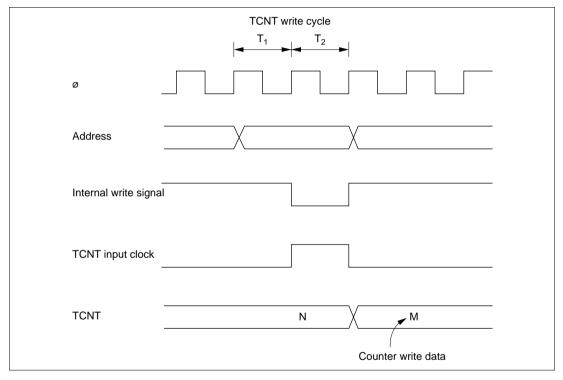


Figure 13-8 Contention between TCNT Write and Increment

13.5.2 Changing Value of CKS2 to CKS0

If bits CKS2 to CKS0 in TCSR are written to while the WDT is operating, errors could occur in the incrementation. Software must stop the watchdog timer (by clearing the TME bit to 0) before changing the value of bits CKS2 to CKS0.

13.5.3 Switching between Watchdog Timer Mode and Interval Timer Mode

If the mode is switched from watchdog timer to interval timer, or vice versa, while the WDT is operating, errors could occur in the incrementation. Software must stop the watchdog timer (by clearing the TME bit to 0) before switching the mode.

13.5.4 System Reset by WDTOVF Signal

If the \overline{WDTOVF} output signal* is input to the \overline{RES} pin of the H8S/2357 Series, the H8S/2357 Series will not be initialized correctly. Make sure that the \overline{WDTOVF} signal* is not input logically to the \overline{RES} pin. To reset the entire system by means of the \overline{WDTOVF} signal*, use the circuit shown in figure 13-9.

Note: * The WDTOVF pin function is not available in the F-ZTAT version, the H8S/2398, H8S/2394, H8S/2392 or H8S/2390.

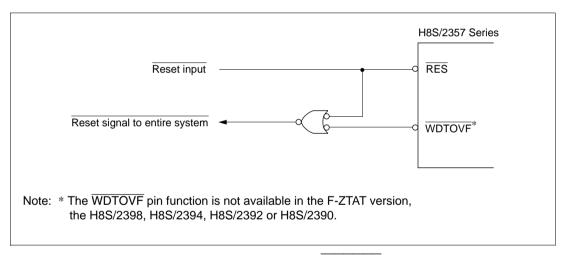


Figure 13-9 Circuit for System Reset by WDTOVF Signal (Example)

13.5.5 Internal Reset in Watchdog Timer Mode

The H8S/2357 Series is not reset internally if TCNT overflows while the RSTE bit is cleared to 0 during watchdog timer operation, but TCNT and TSCR of the WDT are reset.

TCNT, TCSR, and RSTCR cannot be written to while the \overline{WDTOVF} signal* is low. Also note that a read of the WOVF flag is not recognized during this period. To clear the WOVF falg, therefore, read TCSR after the \overline{WDTOVF} signal* goes high, then write 0 to the WOVF flag.

Note: * The WDTOVF pin function is not available in the F-ZTAT version, the H8S/2398, H8S/2394, H8S/2392 or H8S/2390.

Section 14 Serial Communication Interface (SCI)

14.1 Overview

The H8S/2357 Series is equipped with a three-channel serial communication interface (SCI). All three channels have the same functions. The SCI can handle both asynchronous and clocked synchronous serial communication. A function is also provided for serial communication between processors (multiprocessor communication function).

14.1.1 Features

SCI features are listed below.

- Choice of asynchronous or clocked synchronous serial communication mode Asynchronous mode
 - Serial data communication executed using asynchronous system in which synchronization is achieved character by character
 - Serial data communication can be carried out with standard asynchronous communication chips such as a Universal Asynchronous Receiver/Transmitter (UART) or Asynchronous Communication Interface Adapter (ACIA)
 - A multiprocessor communication function is provided that enables serial data communication with a number of processors
 - Choice of 12 serial data transfer formats

Data length : 7 or 8 bits Stop bit length : 1 or 2 bits

Parity : Even, odd, or none

Multiprocessor bit : 1 or 0

— Receive error detection : Parity, overrun, and framing errors

— Break detection : Break can be detected by reading the RxD pin level

directly in case of a framing error

Clocked Synchronous mode

- Serial data communication synchronized with a clock
- Serial data communication can be carried out with other chips that have a synchronous communication function
- One serial data transfer format

— Data length : 8 bits

— Receive error detection : Overrun errors detected

- Full-duplex communication capability
 - The transmitter and receiver are mutually independent, enabling transmission and reception to be executed simultaneously
 - Double-buffering is used in both the transmitter and the receiver, enabling continuous transmission and continuous reception of serial data
- On-chip baud rate generator allows any bit rate to be selected
- Choice of serial clock source: internal clock from baud rate generator or external clock from SCK pin
- Four interrupt sources
 - Four interrupt sources transmit-data-empty, transmit-end, receive-data-full, and receive error that can issue requests independently
 - The transmit-data-empty interrupt and receive data full interrupts can activate the DMA controller (DMAC) or data transfer controller (DTC) to execute data transfer
- Choice of LSB-first or MSB-first transfer
 - Can be selected regardless of the communication mode* (except in the case of asynchronous mode bit data)
- Module stop mode can be set
 - As the initial setting, SCI operation is halted. Register access is enabled by exiting module stop mode.

Note: * Descriptions in this section refer to LSB-first transfer.

14.1.2 Block Diagram

Figure 14-1 shows a block diagram of the SCI.

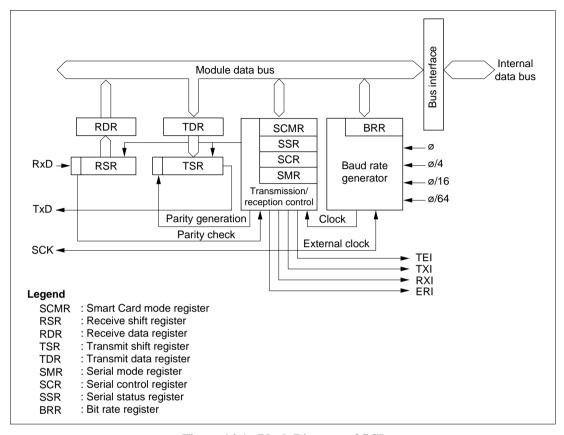


Figure 14-1 Block Diagram of SCI

14.1.3 Pin Configuration

Table 14-1 shows the serial pins for each SCI channel.

Table 14-1 SCI Pins

Channel	Pin Name	Symbol	I/O	Function
0	Serial clock pin 0	SCK0	I/O	SCI0 clock input/output
	Receive data pin 0	RxD0	Input	SCI0 receive data input
	Transmit data pin 0	TxD0	Output	SCI0 transmit data output
1	Serial clock pin 1	SCK1	I/O	SCI1 clock input/output
	Receive data pin 1	RxD1	Input	SCI1 receive data input
	Transmit data pin 1	TxD1	Output	SCI1 transmit data output
2	Serial clock pin 2	SCK2	I/O	SCI2 clock input/output
	Receive data pin 2	RxD2	Input	SCI2 receive data input
	Transmit data pin 2	TxD2	Output	SCI2 transmit data output

14.1.4 Register Configuration

The SCI has the internal registers shown in table 14-2. These registers are used to specify asynchronous mode or clocked synchronous mode, the data format, and the bit rate, and to control transmitter/receiver.

Table 14-2 SCI Registers

Channel	Name	Abbreviation	R/W	Initial Value	Address*1
0	Serial mode register 0	SMR0	R/W	H'00	H'FF78
	Bit rate register 0	BRR0	R/W	H'FF	H'FF79
	Serial control register 0	SCR0	R/W	H'00	H'FF7A
	Transmit data register 0	TDR0	R/W	H'FF	H'FF7B
	Serial status register 0	SSR0	R/(W)*2	H'84	H'FF7C
	Receive data register 0	RDR0	R	H'00	H'FF7D
	Smart card mode register 0	SCMR0	R/W	H'F2	H'FF7E
1	Serial mode register 1	SMR1	R/W	H'00	H'FF80
	Bit rate register 1	BRR1	R/W	H'FF	H'FF81
	Serial control register 1	SCR1	R/W	H'00	H'FF82
	Transmit data register 1	TDR1	R/W	H'FF	H'FF83
	Serial status register 1	SSR1	R/(W)*2	H'84	H'FF84
	Receive data register 1	RDR1	R	H'00	H'FF85
	Smart card mode register 1	SCMR1	R/W	H'F2	H'FF86
2	Serial mode register 2	SMR2	R/W	H'00	H'FF88
	Bit rate register 2	BRR2	R/W	H'FF	H'FF89
	Serial control register 2	SCR2	R/W	H'00	H'FF8A
	Transmit data register 2	TDR2	R/W	H'FF	H'FF8B
	Serial status register 2	SSR2	R/(W)*2	H'84	H'FF8C
	Receive data register 2	RDR2	R	H'00	H'FF8D
	Smart card mode register 2	SCMR2	R/W	H'F2	H'FF8E
All	Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address.

2. Can only be written with 0 for flag clearing.

14.2 Register Descriptions

14.2.1 Receive Shift Register (RSR)

Bit	:	7	6	5	4	3	2	1	0
R/W			_	_	_	_	_	_	_

RSR is a register used to receive serial data.

The SCI sets serial data input from the RxD pin in RSR in the order received, starting with the LSB (bit 0), and converts it to parallel data. When one byte of data has been received, it is transferred to RDR automatically.

RSR cannot be directly read or written to by the CPU.

14.2.2 Receive Data Register (RDR)

Bit	:	7	6	5	4	3	2	1	0
Initial valu	ıe:	0	0	0	0	0	0	0	0
R/W	:	R	R	R	R	R	R	R	R

RDR is a register that stores received serial data.

When the SCI has received one byte of serial data, it transfers the received serial data from RSR to RDR where it is stored, and completes the receive operation. After this, RSR is receive-enabled.

Since RSR and RDR function as a double buffer in this way, enables continuous receive operations to be performed.

RDR is a read-only register, and cannot be written to by the CPU.

RDR is initialized to H'00 by a reset, and in standby mode or module stop mode.

14.2.3 Transmit Shift Register (TSR)

Bit	:	7	6	5	4	3	2	1	0
R/W	:	_	_	_		_		_	

TSR is a register used to transmit serial data.

To perform serial data transmission, the SCI first transfers transmit data from TDR to TSR, then sends the data to the TxD pin starting with the LSB (bit 0).

When transmission of one byte is completed, the next transmit data is transferred from TDR to TSR, and transmission started, automatically. However, data transfer from TDR to TSR is not performed if the TDRE bit in SSR is set to 1.

TSR cannot be directly read or written to by the CPU.

14.2.4 Transmit Data Register (TDR)

Bit	:	7	6	5	4	3	2	1	0
Initial va	ılue :	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

TDR is an 8-bit register that stores data for serial transmission.

When the SCI detects that TSR is empty, it transfers the transmit data written in TDR to TSR and starts serial transmission. Continuous serial transmission can be carried out by writing the next transmit data to TDR during serial transmission of the data in TSR.

TDR can be read or written to by the CPU at all times.

TDR is initialized to H'FF by a reset, and in standby mode or module stop mode.

14.2.5 Serial Mode Register (SMR)

Bit	:	7	6	5	4	3	2	1	0
		C/A	CHR	PE	O/Ē	STOP	MP	CKS1	CKS0
Initial va	ılue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

SMR is an 8-bit register used to set the SCI's serial transfer format and select the baud rate generator clock source.

SMR can be read or written to by the CPU at all times.

SMR is initialized to H'00 by a reset, and by putting the device in standby mode or module stop mode. In the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390, however, the value in SMR is initialized to H'00 by a reset, or in hardware standby mode, but SMR retains its current state when the device enters software standby mode or module stop mode.

Bit 7—Communication Mode (C/\overline{A}): Selects asynchronous mode or clocked synchronous mode as the SCI operating mode.

Bit 7	
C/A	Description

CIA	Description	
0	Asynchronous mode	(Initial value)
1	Clocked synchronous mode	

Bit 6—Character Length (CHR): Selects 7 or 8 bits as the data length in asynchronous mode. In clocked synchronous mode, a fixed data length of 8 bits is used regardless of the CHR setting.

Bit 6 CHR	Description	
0	8-bit data	(Initial value)
1	7-bit data*	

Note: * When 7-bit data is selected, the MSB (bit 7) of TDR is not transmitted, and it is not possible to choose between LSB-first or MSB-first transfer.

Bit 5—Parity Enable (PE): In asynchronous mode, selects whether or not parity bit addition is performed in transmission, and parity bit checking in reception. In clocked synchronous mode and with a multiprocessor format, parity bit addition and checking is not performed, regardless of the PE bit setting.

Bit 5 PE	Description	
0	Parity bit addition and checking disabled	(Initial value)
1	Parity bit addition and checking enabled*	

Note:* When the PE bit is set to 1, the parity (even or odd) specified by the O/\overline{E} bit is added to transmit data before transmission. In reception, the parity bit is checked for the parity (even or odd) specified by the O/\overline{E} bit.

Bit 4—Parity Mode (O/\overline{E}) : Selects either even or odd parity for use in parity addition and checking.

The O/\overline{E} bit setting is only valid when the PE bit is set to 1, enabling parity bit addition and checking, in asynchronous mode. The O/\overline{E} bit setting is invalid in clocked synchronous mode, and when parity addition and checking is disabled in asynchronous mode.

Bit 4 O/E	Description	
0	Even parity* ¹	(Initial value)
1	Odd parity* ²	

- Notes: 1. When even parity is set, parity bit addition is performed in transmission so that the total number of 1 bits in the transmit character plus the parity bit is even.

 In reception, a check is performed to see if the total number of 1 bits in the receive character plus the parity bit is even.
 - 2. When odd parity is set, parity bit addition is performed in transmission so that the total number of 1 bits in the transmit character plus the parity bit is odd.
 In reception, a check is performed to see if the total number of 1 bits in the receive character plus the parity bit is odd.

Bit 3—Stop Bit Length (STOP): Selects 1 or 2 bits as the stop bit length in asynchronous mode. The STOP bits setting is only valid in asynchronous mode. If clocked synchronous mode is set the STOP bit setting is invalid since stop bits are not added.

Bit 3 STOP	Description
0	1 stop bit: In transmission, a single 1 bit (stop bit) is added to the end of a transmit character before it is sent. (Initial value)
1	2 stop bits: In transmission, two 1 bits (stop bits) are added to the end of a transmit character before it is sent.

In reception, only the first stop bit is checked, regardless of the STOP bit setting. If the second stop bit is 1, it is treated as a stop bit; if it is 0, it is treated as the start bit of the next transmit character.

Bit 2—Multiprocessor Mode (MP): Selects multiprocessor format. When multiprocessor format is selected, the PE bit and O/\overline{E} bit parity settings are invalid. The MP bit setting is only valid in asynchronous mode; it is invalid in clocked synchronous mode.

For details of the multiprocessor communication function, see section 14.3.3, Multiprocessor Communication Function.

Bit 2 MP	Description	
0	Multiprocessor function disabled	(Initial value)
1	Multiprocessor format selected	

Bits 1 and 0—Clock Select 1 and 0 (CKS1, CKS0): These bits select the clock source for the baud rate generator. The clock source can be selected from \emptyset , $\emptyset/4$, $\emptyset/16$, and $\emptyset/64$, according to the setting of bits CKS1 and CKS0.

For the relation between the clock source, the bit rate register setting, and the baud rate, see section 14.2.8, Bit Rate Register.

Bit 1 CKS1	Bit 0 CKS0	Description	
0	0	ø clock	(Initial value)
	1	ø/4 clock	
1	0	ø/16 clock	
	1	ø/64 clock	

14.2.6 Serial Control Register (SCR)

Bit	:	7	6	5	4	3	2	1	0
		TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

SCR is a register that performs enabling or disabling of SCI transfer operations, serial clock output in asynchronous mode, and interrupt requests, and selection of the serial clock source.

SCR can be read or written to by the CPU at all times.

SCR is initialized to H'00 by a reset, and by putting the device in standby mode or module stop mode. In the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390, however, the value in SCR is initialized to H'00 by a reset, or in hardware standby mode, but SCR retains its current state when the device enters software standby mode or module stop mode.

Bit 7—Transmit Interrupt Enable (TIE): Enables or disables transmit data empty interrupt (TXI) request generation when serial transmit data is transferred from TDR to TSR and the TDRE flag in SSR is set to 1.

Bit 7 TIE	Description	
0	Transmit data empty interrupt (TXI) requests disabled*	(Initial value)
1	Transmit data empty interrupt (TXI) requests enabled	

Note:* TXI interrupt request cancellation can be performed by reading 1 from the TDRE flag, then clearing it to 0, or clearing the TIE bit to 0.

Bit 6—Receive Interrupt Enable (RIE): Enables or disables receive data full interrupt (RXI) request and receive error interrupt (ERI) request generation when serial receive data is transferred from RSR to RDR and the RDRF flag in SSR is set to 1.

Bit 6 RIE	Description
0	Receive data full interrupt (RXI) request and receive error interrupt (ERI) request disabled* (Initial value)
1	Receive data full interrupt (RXI) request and receive error interrupt (ERI) request enabled

Note: * RXI and ERI interrupt request cancellation can be performed by reading 1 from the RDRF flag, or the FER, PER, or ORER flag, then clearing the flag to 0, or clearing the RIE bit to 0.

Bit 5—Transmit Enable (TE): Enables or disables the start of serial transmission by the SCI.

Bit 5 TE		Description
0		Transmission disabled*1 (Initial value
1		Transmission enabled*2
Notes:	1.	The TDRE flag in SSR is fixed at 1.
	2.	In this state, serial transmission is started when transmit data is written to TDR and the TDRE flag in SSR is cleared to 0.
		SMR setting must be performed to decide the transfer format before setting the TE bit

Bit 4—Receive Enable (RE): Enables or disables the start of serial reception by the SCI.

Bit 4 RE		Description	
0		Reception disabled* ¹ (Initial value	ıe)
1		Reception enabled*2	
Notes:	1.	Clearing the RE bit to 0 does not affect the RDRF, FER, PER, and ORER flags, which retain their states.	1
	2.	Serial reception is started in this state when a start bit is detected in asynchronous mode or serial clock input is detected in clocked synchronous mode.	

SMR setting must be performed to decide the transfer format before setting the RE bit

to 1.

to 1.

Bit 3—Multiprocessor Interrupt Enable (MPIE): Enables or disables multiprocessor interrupts. The MPIE bit setting is only valid in asynchronous mode when the MP bit in SMR is set to 1.

The MPIE bit setting is invalid in clocked synchronous mode or when the MP bit is cleared to 0.

Bit 3 MPIE	Description	
0	Multiprocessor interrupts disabled (normal reception performed)	(Initial value)
	[Clearing conditions]	
	 When the MPIE bit is cleared to 0 	
	 When MPB= 1 data is received 	
1	Multiprocessor interrupts enabled*	
	Receive interrupt (RXI) requests, receive error interrupt (ERI) request of the RDRF, FER, and ORER flags in SSR are disabled until data with multiprocessor bit set to 1 is received.	•

Note: *When receive data including MPB = 0 is received, receive data transfer from RSR to RDR, receive error detection, and setting of the RDRF, FER, and ORER flags in SSR, is not performed. When receive data including MPB = 1 is received, the MPB bit in SSR is set to 1, the MPIE bit is cleared to 0 automatically, and generation of RXI and ERI interrupts (when the TIE and RIE bits in SCR are set to 1) and FER and ORER flag setting is enabled.

Bit 2—Transmit End Interrupt Enable (TEIE): Enables or disables transmit end interrupt (TEI) request generation when there is no valid transmit data in TDR in MSB data transmission.

Bit 2 TEIE	Description	
0	Transmit end interrupt (TEI) request disabled*	(Initial value)
1	Transmit end interrupt (TEI) request enabled*	

Note: *TEI cancellation can be performed by reading 1 from the TDRE flag in SSR, then clearing it to 0 and clearing the TEND flag to 0, or clearing the TEIE bit to 0.

Bits 1 and 0—Clock Enable 1 and 0 (CKE1, CKE0): These bits are used to select the SCI clock source and enable or disable clock output from the SCK pin. The combination of the CKE1 and CKE0 bits determines whether the SCK pin functions as an I/O port, the serial clock output pin, or the serial clock input pin.

The setting of the CKE0 bit, however, is only valid for internal clock operation (CKE1 = 0) in asynchronous mode. The CKE0 bit setting is invalid in clocked synchronous mode, and in the case of external clock operation (CKE1 = 1). Note that the SCI's operating mode must be decided using SMR before setting the CKE1 and CKE0 bits.

For details of clock source selection, see table 14-9 in section 14-3, Operation.

Bit 1 CKE1	Bit 0 CKE0	Description				
0	0	Asynchronous mode	Internal clock/SCK pin functions as I/O port*1			
		Clocked synchronous mode	Internal clock/SCK pin functions as serial clock output			
	1	Asynchronous mode	Internal clock/SCK pin functions as clock output*2			
		Clocked synchronous mode	Internal clock/SCK pin functions as serial clock output			
1	0	Asynchronous mode	External clock/SCK pin functions as clock input*3			
		Clocked synchronous mode	External clock/SCK pin functions as serial clock input			
	1	Asynchronous mode	External clock/SCK pin functions as clock input*3			
		Clocked synchronous mode	External clock/SCK pin functions as serial clock input			

Notes: 1. Initial value

- 2. Outputs a clock of the same frequency as the bit rate.
- 3. Inputs a clock with a frequency 16 times the bit rate.

14.2.7 Serial Status Register (SSR)

Bit	:	7	6	5	4	3	2	1	0
		TDRE	RDRF	ORER	FER	PER	TEND	MPB	MPBT
Initial va	alue :	1	0	0	0	0	1	0	0
R/W	:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W

Note: * Only 0 can be written, to clear the flag.

When the TE bit in SCR is 0

SSR is an 8-bit register containing status flags that indicate the operating status of the SCI, and multiprocessor bits.

SSR can be read or written to by the CPU at all times. However, 1 cannot be written to flags TDRE, RDRF, ORER, PER, and FER. Also note that in order to clear these flags they must be read as 1 beforehand. The TEND flag and MPB flag are read-only flags and cannot be modified.

SSR is initialized to H'84 by a reset, and by putting the device in standby mode or module stop mode.

Bit 7—Transmit Data Register Empty (TDRE): Indicates that data has been transferred from TDR to TSR and the next serial data can be written to TDR.

Bit 7
TDRE Description

0 [Clearing conditions]

• When 0 is written to TDRE after reading TDRE = 1

• When the DMAC or DTC is activated by a TXI interrupt and write data to TDR

1 [Setting conditions] (Initial value)

When data is transferred from TDR to TSR and data can be written to TDR

Bit 6—Receive Data Register Full (RDRF): Indicates that the received data is stored in RDR.

Bit 6	
RDRF	Description
0	[Clearing conditions] (Initial value)
	 When 0 is written to RDRF after reading RDRF = 1
	When the DMAC or DTC is activated by an RXI interrupt and read data from RDR
1	[Setting condition]
	When serial reception ends normally and receive data is transferred from RSR to RDR
Noto:	DDP and the DDPE flog are not affected and retain their provious values when an error is

Note: RDR and the RDRF flag are not affected and retain their previous values when an error is detected during reception or when the RE bit in SCR is cleared to 0.

If reception of the next data is completed while the RDRF flag is still set to 1, an overrun error will occur and the receive data will be lost.

Bit 5—Overrun Error (ORER): Indicates that an overrun error occurred during reception, causing abnormal termination.

Bit 5 ORER		Description	
0		[Clearing condition]	(Initial value)*1
		When 0 is written to ORER after reading ORER = 1	
1		[Setting condition]	
		When the next serial reception is completed while RDRF = 1	
Notes:	1.	The ORER flag is not affected and retains its previous state when the cleared to 0.	RE bit in SCR is
	2.	The receive data prior to the overrun error is retained in RDR, and the subsequently is lost. Also, subsequent serial reception cannot be con ORER flag is set to 1. In clocked synchronous mode, serial transmiss continued, either.	tinued while the

Bit 4—Framing Error (FER): Indicates that a framing error occurred during reception in asynchronous mode, causing abnormal termination.

Bit 4 FER		Description	
0		[Clearing condition]	(Initial value)*1
		When 0 is written to FER after reading FER = 1	
1		[Setting condition]	
		When the SCI checks whether the stop bit at the end of the receive data reception ends, and the stop bit is 0 $^{\ast^2}$	ta when
Notes:	1.	The FER flag is not affected and retains its previous state when the RE cleared to 0.	bit in SCR is
	2.	In 2-stop-bit mode, only the first stop bit is checked for a value of 0; the is not checked. If a framing error occurs, the receive data is transferred RDRF flag is not set. Also, subsequent serial reception cannot be continued, either.	to RDR but the nued while the

Bit 3—Parity Error (PER): Indicates that a parity error occurred during reception using parity addition in asynchronous mode, causing abnormal termination.

Bit 3			
PER		Description	
0		[Clearing condition]	(Initial value)*1
		When 0 is written to PER after reading PER = 1	
1		[Setting condition] When, in reception, the number of 1 bits in the receive data plus th match the parity setting (even or odd) specified by the O/E bit in SI	
Notes:	1.	The PER flag is not affected and retains its previous state when the cleared to 0.	RE bit in SCR is
	2.	If a parity error occurs, the receive data is transferred to RDR but th set. Also, subsequent serial reception cannot be continued while the 1. In clocked synchronous mode, serial transmission cannot be continued to the continued while the serial transmission cannot be continued to the continue	e PER flag is set to

Bit 2—Transmit End (TEND): Indicates that there is no valid data in TDR when the last bit of the transmit character is sent, and transmission has been ended.

The TEND flag is read-only and cannot be modified.

Bit 2 TEND	Description	
0	[Clearing conditions]	_
	 When 0 is written to TDRE after reading TDRE = 1 	
	When the DMAC or DTC is activated by a TXI interrupt and was a time.	vrite data to TDR
1	[Setting conditions]	(Initial value)
	 When the TE bit in SCR is 0 	
	When TDRE = 1 at transmission of the last bit of a 1-byte ser	rial transmit character

Bit 1—Multiprocessor Bit (MPB): When reception is performed using multiprocessor format in asynchronous mode, MPB stores the multiprocessor bit in the receive data.

MPB is a read-only bit, and cannot be modified.

Bit 1 MPB	Description	
0	[Clearing condition] When data with a 0 multiprocessor bit is received	(Initial value)*
1	[Setting condition] When data with a 1 multiprocessor bit is received	

Note: * Retains its previous state when the RE bit in SCR is cleared to 0 with multiprocessor format.

Bit 0—Multiprocessor Bit Transfer (MPBT): When transmission is performed using multiprocessor format in asynchronous mode, MPBT stores the multiprocessor bit to be added to the transmit data.

The MPBT bit setting is invalid when multiprocessor format is not used, when not transmitting, and in clocked synchronous mode.

Bit 0 MPBT	Description	
0	Data with a 0 multiprocessor bit is transmitted	(Initial value)
1	Data with a 1 multiprocessor bit is transmitted	

14.2.8 Bit Rate Register (BRR)

Bit	:	7	6	5	4	3	2	1	0
Initial va	alue :	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

BRR is an 8-bit register that sets the serial transfer bit rate in accordance with the baud rate generator operating clock selected by bits CKS1 and CKS0 in SMR.

BRR can be read or written to by the CPU at all times.

BRR is initialized to H'FF by a reset, and by putting the device in standby mode or module stop mode. In the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390, however, the value in BRR is initialized to H'FF by a reset, or in hardware standby mode, but BRR retains its current state when the device enters software standby mode or module stop mode.

As baud rate generator control is performed independently for each channel, different values can be set for each channel.

Table 14-3 shows sample BRR settings in asynchronous mode, and table 14-4 shows sample BRR settings in clocked synchronous mode.

Table 14-3 BRR Settings for Various Bit Rates (Asynchronous Mode)

	ø = 2 MHz			Ø	ø = 2.097152 MHz			ø = 2.4576 MHz			ø = 3 MHz		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	1	141	0.03	1	148	-0.04	1	174	-0.26	1	212	0.03	
150	1	103	0.16	1	108	0.21	1	127	0.00	1	155	0.16	
300	0	207	0.16	0	217	0.21	0	255	0.00	1	77	0.16	
600	0	103	0.16	0	108	0.21	0	127	0.00	0	155	0.16	
1200	0	51	0.16	0	54	-0.70	0	63	0.00	0	77	0.16	
2400	0	25	0.16	0	26	1.14	0	31	0.00	0	38	0.16	
4800	0	12	0.16	0	13	-2.48	0	15	0.00	0	19	-2.34	
9600	0	6	_	0	6	-2.48	0	7	0.00	0	9	-2.34	
19200	0	2	_	0	2	_	0	3	0.00	0	4	-2.34	
31250	0	1	0.00	0	1	_	0	1	_	0	2	0.00	
38400	0	1	_	0	1	_	0	1	0.00	_	_	_	

	ø = 3.6864 MHz				ø = 4 MHz			ø = 4.9152 MHz			ø = 5 MHz		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	2	64	0.70	2	70	0.03	2	86	0.31	2	88	-0.25	
150	1	191	0.00	1	207	0.16	1	255	0.00	2	64	0.16	
300	1	95	0.00	1	103	0.16	1	127	0.00	1	129	0.16	
600	0	191	0.00	0	207	0.16	0	255	0.00	1	64	0.16	
1200	0	95	0.00	0	103	0.16	0	127	0.00	0	129	0.16	
2400	0	47	0.00	0	51	0.16	0	63	0.00	0	64	0.16	
4800	0	23	0.00	0	25	0.16	0	31	0.00	0	32	-1.36	
9600	0	11	0.00	0	12	0.16	0	15	0.00	0	15	1.73	
19200	0	5	0.00	0	6	_	0	7	0.00	0	7	1.73	
31250	_	_	_	0	3	0.00	0	4	-1.70	0	4	0.00	
38400	0	2	0.00	0	2	_	0	3	0.00	0	3	1.73	

	ø = 6 MHz				ø = 6.144 MHz			ø = 7.3728 MHz			ø = 8 MHz		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	2	106	-0.44	2	108	0.08	2	130	-0.07	2	141	0.03	
150	2	77	0.16	2	79	0.00	2	95	0.00	2	103	0.16	
300	1	155	0.16	1	159	0.00	1	191	0.00	1	207	0.16	
600	1	77	0.16	1	79	0.00	1	95	0.00	1	103	0.16	
1200	0	155	0.16	0	159	0.00	0	191	0.00	0	207	0.16	
2400	0	77	0.16	0	79	0.00	0	95	0.00	0	103	0.16	
4800	0	38	0.16	0	39	0.00	0	47	0.00	0	51	0.16	
9600	0	19	-2.34	0	19	0.00	0	23	0.00	0	25	0.16	
19200	0	9	-2.34	0	9	0.00	0	11	0.00	0	12	0.16	
31250	0	5	0.00	0	5	2.40	0	6	_	0	7	0.00	
38400	0	4	-2.34	0	4	0.00	0	5	0.00	0	6	_	

	ø = 9.8304 MHz			ø = 10 MHz			ø = 12 MHz			ø = 12.288 MHz		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)
110	2	174	-0.26	2	177	-0.25	2	212	0.03	2	217	0.08
150	2	127	0.00	2	129	0.16	2	155	0.16	2	159	0.00
300	1	255	0.00	2	64	0.16	2	77	0.16	2	79	0.00
600	1	127	0.00	1	129	0.16	1	155	0.16	1	159	0.00
1200	0	255	0.00	1	64	0.16	1	77	0.16	1	79	0.00
2400	0	127	0.00	0	129	0.16	0	155	0.16	0	159	0.00
4800	0	63	0.00	0	64	0.16	0	77	0.16	0	79	0.00
9600	0	31	0.00	0	32	-1.36	0	38	0.16	0	39	0.00
19200	0	15	0.00	0	15	1.73	0	19	-2.34	0	19	0.00
31250	0	9	-1.70	0	9	0.00	0	11	0.00	0	11	2.40
38400	0	7	0.00	0	7	1.73	0	9	-2.34	0	9	0.00

		ø = 14 l	ИHz	Ø	ø = 14.7456 MHz			ø = 16 MHz			ø = 17.2032 MHz		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	2	248	-0.17	3	64	0.70	3	70	0.03	3	75	0.48	
150	2	181	0.16	2	191	0.00	2	207	0.16	2	223	0.00	
300	2	90	0.16	2	95	0.00	2	103	0.16	2	111	0.00	
600	1	181	0.16	1	191	0.00	1	207	0.16	1	223	0.00	
1200	1	90	0.16	1	95	0.00	1	103	0.16	1	111	0.00	
2400	0	181	0.16	0	191	0.00	0	207	0.16	0	223	0.00	
4800	0	90	0.16	0	95	0.00	0	103	0.16	0	111	0.00	
9600	0	45	-0.93	0	47	0.00	0	51	0.16	0	55	0.00	
19200	0	22	-0.93	0	23	0.00	0	25	0.16	0	27	0.00	
31250	0	13	0.00	0	14	-1.70	0	15	0.00	0	16	1.20	
38400	0	10	_	0	11	0.00	0	12	0.16	0	13	0.00	

		ø = 18 MHz ø = 19.6608 MHz						ø = 20 MHz				
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)			
110	3	79	-0.12	3	86	0.31	3	88	-0.25			
150	2	233	0.16	2	255	0.00	3	64	0.16			
300	2	116	0.16	2	127	0.00	2	129	0.16			
600	1	233	0.16	1	255	0.00	2	64	0.16			
1200	1	116	0.16	1	127	0.00	1	129	0.16			
2400	0	233	0.16	0	255	0.00	1	64	0.16			
4800	0	116	0.16	0	127	0.00	0	129	0.16			
9600	0	58	-0.69	0	63	0.00	0	64	0.16			
19200	0	28	1.02	0	31	0.00	0	32	-1.36			
31250	0	17	0.00	0	19	-1.70	0	19	0.00			
38400	0	14	-2.34	0	15	0.00	0	15	1.73			

 Table 14-4
 BRR Settings for Various Bit Rates (Clocked Synchronous Mode)

Bit Rate	ø = 2 MHz		ø = 4 MHz		ø = 8 MHz		ø = 10 MHz		ø = 16 MHz		ø = 20 MHz	
(bit/s)	n	N	n	N	n	N	n	N	n	N	n	N
110	3	70										
250	2	124	2	249	3	124	_	_	3	249		
500	1	249	2	124	2	249	_	_	3	124	_	_
1 k	1	124	1	249	2	124	_	_	2	249	_	_
2.5 k	0	199	1	99	1	199	1	249	2	99	2	124
5 k	0	99	0	199	1	99	1	124	1	199	1	249
10 k	0	49	0	99	0	199	0	249	1	99	1	124
25 k	0	19	0	39	0	79	0	99	0	159	0	199
50 k	0	9	0	19	0	39	0	49	0	79	0	99
100 k	0	4	0	9	0	19	0	24	0	39	0	49
250 k	0	1	0	3	0	7	0	9	0	15	0	19
500 k	0	0*	0	1	0	3	0	4	0	7	0	9
1 M			0	0*	0	1			0	3	0	4
2.5 M							0	0*			0	1
5 M											0	0*

Note: As far as possible, the setting should be made so that the error is no more than 1%.

Legend

Blank: Cannot be set.

— : Can be set, but there will be a degree of error.

* : Continuous transfer is not possible.

The BRR setting is found from the following formulas.

Asynchronous mode:

$$N = \frac{\emptyset}{64 \times 2^{2n-1} \times B} \times 10^6 - 1$$

Clocked synchronous mode:

$$N = \frac{\emptyset}{8 \times 2^{2n-1} \times B} \times 10^6 - 1$$

Where B: Bit rate (bit/s)

N: BRR setting for baud rate generator (0 N 255)

ø: Operating frequency (MHz)

n: Baud rate generator input clock (n=0 to 3) (See the table below for the relation between n and the clock.)

		SM	IR Setting
n	Clock	CKS1	CKS0
0	Ø	0	0
1	ø/4	0	1
2	ø/16	1	0
3	ø/64	1	1

The bit rate error in asynchronous mode is found from the following formula:

Error (%) = {
$$\frac{\emptyset \times 10^6}{(N+1) \times B \times 64 \times 2^{2n-1}} - 1} \times 100$$

Table 14-5 shows the maximum bit rate for each frequency in asynchronous mode. Tables 14-6 and 14-7 show the maximum bit rates with external clock input.

 Table 14-5
 Maximum Bit Rate for Each Frequency (Asynchronous Mode)

ø (MHz)	Maximum Bit Rate (bit/s)	n	N
2	62500	0	0
2.097152	65536	0	0
2.4576	76800	0	0
3	93750	0	0
3.6864	115200	0	0
4	125000	0	0
4.9152	153600	0	0
5	156250	0	0
6	187500	0	0
6.144	192000	0	0
7.3728	230400	0	0
8	250000	0	0
9.8304	307200	0	0
10	312500	0	0
12	375000	0	0
12.288	384000	0	0
14	437500	0	0
14.7456	460800	0	0
16	500000	0	0
17.2032	537600	0	0
18	562500	0	0
19.6608	614400	0	0
20	625000	0	0

 Table 14-6
 Maximum Bit Rate with External Clock Input (Asynchronous Mode)

ø (MHz)	External Input Clock (MHz)	Maximum Bit Rate (bit/s)
2	0.5000	31250
2.097152	0.5243	32768
2.4576	0.6144	38400
3	0.7500	46875
3.6864	0.9216	57600
4	1.0000	62500
4.9152	1.2288	76800
5	1.2500	78125
6	1.5000	93750
6.144	1.5360	96000
7.3728	1.8432	115200
8	2.0000	125000
9.8304	2.4576	153600
10	2.5000	156250
12	3.0000	187500
12.288	3.0720	192000
14	3.5000	218750
14.7456	3.6864	230400
16	4.0000	250000
17.2032	4.3008	268800
18	4.5000	281250
19.6608	4.9152	307200
20	5.0000	312500

Table 14-7 Maximum Bit Rate with External Clock Input (Clocked Synchronous Mode)

ø (MHz)	External Input Clock (MHz)	Maximum Bit Rate (bit/s)
2	0.3333	333333.3
4	0.6667	666666.7
6	1.0000	1000000.0
8	1.3333	1333333.3
10	1.6667	1666666.7
12	2.0000	2000000.0
14	2.3333	2333333.3
16	2.6667	2666666.7
18	3.0000	3000000.0
20	3.3333	3333333.3

14.2.9 Smart Card Mode Register (SCMR)

Bit	:	7	6	5	4	3	2	1	0
		_		_	_	SDIR	SINV		SMIF
Initial va	lue :	1	1	1	1	0	0	1	0
R/W	:	_	_	_	_	R/W	R/W	_	R/W

SCMR selects LSB-first or MSB-first by means of bit SDIR. Except in the case of asynchronous mode 7-bit data, LSB-first or MSB-first can be selected regardless of the serial communication mode. The descriptions in this chapter refer to LSB-first transfer.

For details of the other bits in SCMR, see 15.2.1, Smart Card Mode Register (SCMR).

SCMR is initialized to H'F2 by a reset, and by putting the device in standby mode or module stop mode. In the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390, however, the value in SCMR is initialized to H'F2 by a reset, or in hardware standby mode, but SCMR retains its current state when the device enters software standby mode or module stop mode.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 1.

Bit 3—Smart Card Data Transfer Direction (SDIR): Selects the serial/parallel conversion format.

This bit is valid when 8-bit data is used as the transmit/receive format.

Bit 3 SDIR	Description	
0	TDR contents are transmitted LSB-first	(Initial value)
	Receive data is stored in RDR LSB-first	
1	TDR contents are transmitted MSB-first	
	Receive data is stored in RDR MSB-first	

Bit 2—Smart Card Data Invert (SINV): When the smart card interface operates as a normal SCI, 0 should be written in this bit.

Bit 1—Reserved: This bit cannot be modified always read as 1.

Bit 0—Smart Card Interface Mode Select (SMIF): When the smart card interface operates as a normal SCI, 0 should be written in this bit.

14.2.10 Module Stop Control Register (MSTPCR)

					MST	PCRH	ł			MSTPCRL							
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial val	lue :	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the corresponding bit of bits MSTP7 to MSTP5 is set to 1, SCI operation stops at the end of the bus cycle and a transition is made to module stop mode. Registers cannot be read or written to in module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 7—Module Stop (MSTP7): Specifies the SCI channel 2 module stop mode.

Bit 7 MSTP7 Description 0 SCI channel 2 module stop mode cleared 1 SCI channel 2 module stop mode set (Initial value)

Bit 6—Module Stop (MSTP6): Specifies the SCI channel 1 module stop mode.

Bit 6 MSTP6	Description	
0	SCI channel 1 module stop mode cleared	
1	SCI channel 1 module stop mode set	(Initial value)

Bit 5—Module Stop (MSTP5): Specifies the SCI channel 0 module stop mode.

Bit 5 MSTP5	Description	
0	SCI channel 0 module stop mode cleared	
1	SCI channel 0 module stop mode set	(Initial value)

14.3 Operation

14.3.1 Overview

The SCI can carry out serial communication in two modes: asynchronous mode in which synchronization is achieved character by character, and clocked synchronous mode in which synchronization is achieved with clock pulses.

Selection of asynchronous or clocked synchronous mode and the transmission format is made using SMR as shown in table 14-8. The SCI clock is determined by a combination of the C/\overline{A} bit in SMR and the CKE1 and CKE0 bits in SCR, as shown in table 14-9.

Asynchronous Mode

- Data length: Choice of 7 or 8 bits
- Choice of parity addition, multiprocessor bit addition, and addition of 1 or 2 stop bits (the combination of these parameters determines the transfer format and character length)
- Detection of framing, parity, and overrun errors, and breaks, during reception
- Choice of internal or external clock as SCI clock source
 - When internal clock is selected:
 - The SCI operates on the baud rate generator clock and a clock with the same frequency as the bit rate can be output
 - When external clock is selected:
 - A clock with a frequency of 16 times the bit rate must be input (the on-chip baud rate generator is not used)

Clocked Synchronous Mode

- Transfer format: Fixed 8-bit data
- Detection of overrun errors during reception
- Choice of internal or external clock as SCI clock source
 - When internal clock is selected:
 - The SCI operates on the baud rate generator clock and a serial clock is output off-chip
 - When external clock is selected:
 - The on-chip baud rate generator is not used, and the SCI operates on the input serial clock

Table 14-8 SMR Settings and Serial Transfer Format Selection

SMR Settings							SCI Transfe	sfer Format			
Bit 7	Bit 6	Bit 2	Bit 5	Bit 3	_ _ Mode	Data Length	Multi Processor Bit	Parity Bit	Stop Bit Length		
0 0 	0	0	0	0 /	Asynchronous 8-bit data mode 7-bit data	No	No	1 bit			
		1		1					2 bits		
			1	0				Yes	1 bit		
				1					2 bits		
	1	_	0 0	0		7-bit data		No	1 bit		
				1	_				2 bits		
					1	0	_			Yes	1 bit
				1	_				2 bits		
	0	1	_	0	Asynchronous	8-bit data	Yes	No	1 bit		
	1			1 mode (multi-		<u></u>		2 bits			
			_	0	[−] processor _format)	7-bit data			1 bit		
			_	1				_	2 bits		
1	_	_	_	_	Clocked synchronous mode	8-bit data	No		None		

Table 14-9 SMR and SCR Settings and SCI Clock Source Selection

SMR	SCR Setting				SCI Transmit/Receive Clock	
Bit 7	Bit 1	Bit 0	_	Clock		
C/A	CKE1	CKE0	Mode	Source	SCK Pin Function	
0	0	0	Asynchronous	Internal	SCI does not use SCK pin	
		1	mode		Outputs clock with same frequency as bit rate	
	1	0	_	External	Inputs clock with frequency of 16 times	
		1	_		the bit rate	
1	0	0	Clocked	Internal	Outputs serial clock	
		1	synchronous			
	1	0	mode	External	Inputs serial clock	
		1				

14.3.2 Operation in Asynchronous Mode

In asynchronous mode, characters are sent or received, each preceded by a start bit indicating the start of communication and one or two stop bits indicating the end of communication. Serial communication is thus carried out with synchronization established on a character-by-character basis.

Inside the SCI, the transmitter and receiver are independent units, enabling full-duplex communication. Both the transmitter and the receiver also have a double-buffered structure, so that data can be read or written during transmission or reception, enabling continuous data transfer.

Figure 14-2 shows the general format for asynchronous serial communication.

In asynchronous serial communication, the transmission line is usually held in the mark state (high level). The SCI monitors the transmission line, and when it goes to the space state (low level), recognizes a start bit and starts serial communication.

One serial communication character consists of a start bit (low level), followed by data (in LSB-first order), a parity bit (high or low level), and finally one or two stop bits (high level).

In asynchronous mode, the SCI performs synchronization at the falling edge of the start bit in reception. The SCI samples the data on the 8th pulse of a clock with a frequency of 16 times the length of one bit, so that the transfer data is latched at the center of each bit.

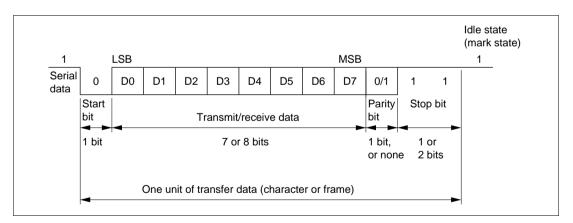


Figure 14-2 Data Format in Asynchronous Communication (Example with 8-Bit Data, Parity, Two Stop Bits)

Data Transfer Format: Table 14-10 shows the data transfer formats that can be used in asynchronous mode. Any of 12 transfer formats can be selected according to the SMR setting.

Table 14-10 Serial Transfer Formats (Asynchronous Mode)

SMR Settings				Serial Transfer Format and Frame Length		
CHR	PE	MP	STOP	1 2 3 4 5 6 7 8 9 10 11 12		
0	0	0	0	S 8-bit data STOP		
0	0	0	1	S 8-bit data STOP STOP		
0	1	0	0	S 8-bit data P STOP		
0	1	0	1	S 8-bit data P STOP STOP		
1	0	0	0	S 7-bit data STOP		
1	0	0	1	S 7-bit data STOP STOP		
1	1	0	0	S 7-bit data P STOP		
1	1	0	1	S 7-bit data P STOP STOP		
0	_	1	0	S 8-bit data MPB STOP		
0	1	1	1	S 8-bit data MPB STOP STOP		
1	_	1	0	S 7-bit data MPB STOP		
1	_	1	1	S 7-bit data MPB STOP STOP		

Legend

S : Start bit STOP : Stop bit P : Parity bit

MPB : Multiprocessor bit

Clock: Either an internal clock generated by the on-chip baud rate generator or an external clock input at the SCK pin can be selected as the SCI's serial clock, according to the setting of the C/\overline{A} bit in SMR and the CKE1 and CKE0 bits in SCR. For details of SCI clock source selection, see table 14-9.

When an external clock is input at the SCK pin, the clock frequency should be 16 times the bit rate used.

When the SCI is operated on an internal clock, the clock can be output from the SCK pin. The frequency of the clock output in this case is equal to the bit rate, and the phase is such that the rising edge of the clock is in the middle of the transmit data, as shown in figure 14-3.

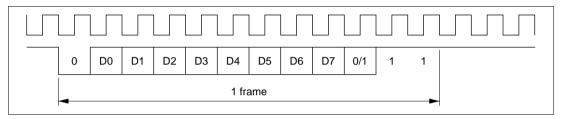


Figure 14-3 Relation between Output Clock and Transfer Data Phase (Asynchronous Mode)

Data Transfer Operations:

• SCI initialization (asynchronous mode)

Before transmitting and receiving data, you should first clear the TE and RE bits in SCR to 0, then initialize the SCI as described below.

When the operating mode, transfer format, etc., is changed, the TE and RE bits must be cleared to 0 before making the change using the following procedure. When the TE bit is cleared to 0, the TDRE flag is set to 1 and TSR is initialized. Note that clearing the RE bit to 0 does not change the contents of the RDRF, PER, FER, and ORER flags, or the contents of RDR.

When an external clock is used the clock should not be stopped during operation, including initialization, since operation is uncertain.

Figure 14-4 shows a sample SCI initialization flowchart.

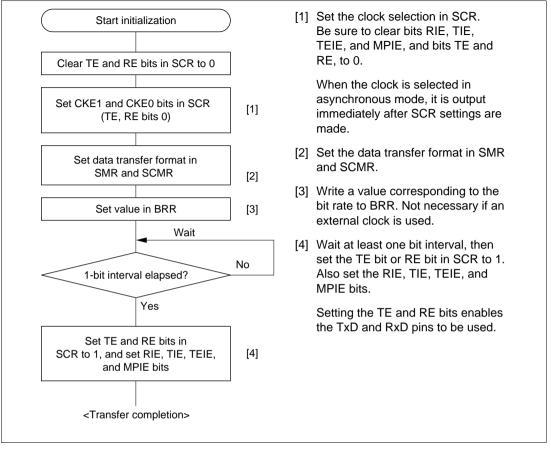


Figure 14-4 Sample SCI Initialization Flowchart

Serial data transmission (asynchronous mode)
 Figure 14-5 shows a sample flowchart for serial transmission.

The following procedure should be used for serial data transmission.

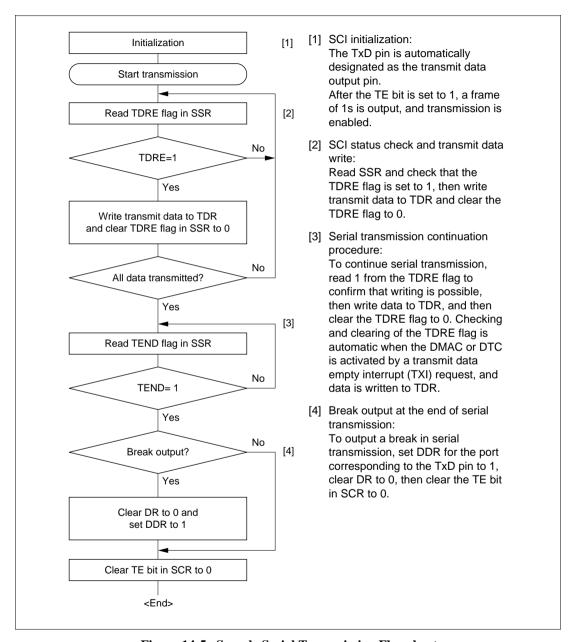


Figure 14-5 Sample Serial Transmission Flowchart

In serial transmission, the SCI operates as described below.

- [1] The SCI monitors the TDRE flag in SSR, and if is 0, recognizes that data has been written to TDR, and transfers the data from TDR to TSR.
- [2] After transferring data from TDR to TSR, the SCI sets the TDRE flag to 1 and starts transmission.

If the TIE bit is set to 1 at this time, a transmit data empty interrupt (TXI) is generated.

The serial transmit data is sent from the TxD pin in the following order.

[a] Start bit:

One 0-bit is output.

[b] Transmit data:

8-bit or 7-bit data is output in LSB-first order.

[c] Parity bit or multiprocessor bit:

One parity bit (even or odd parity), or one multiprocessor bit is output.

A format in which neither a parity bit nor a multiprocessor bit is output can also be selected.

[d] Stop bit(s):

One or two 1-bits (stop bits) are output.

[e] Mark state:

1 is output continuously until the start bit that starts the next transmission is sent.

[3] The SCI checks the TDRE flag at the timing for sending the stop bit.

If the TDRE flag is cleared to 0, the data is transferred from TDR to TSR, the stop bit is sent, and then serial transmission of the next frame is started.

If the TDRE flag is set to 1, the TEND flag in SSR is set to 1, the stop bit is sent, and then the "mark state" is entered in which 1 is output continuously. If the TEIE bit in SCR is set to 1 at this time, a TEI interrupt request is generated.

Figure 14-6 shows an example of the operation for transmission in asynchronous mode.

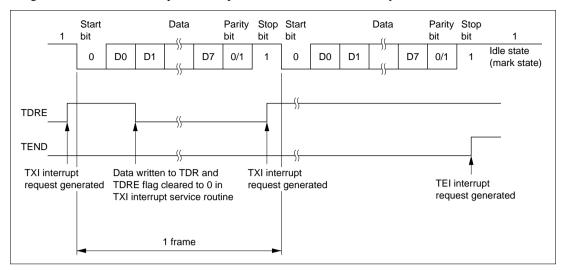


Figure 14-6 Example of Operation in Transmission in Asynchronous Mode (Example with 8-Bit Data, Parity, One Stop Bit)

Serial data reception (asynchronous mode)
 Figure 14-7 shows a sample flowchart for serial reception.

The following procedure should be used for serial data reception.

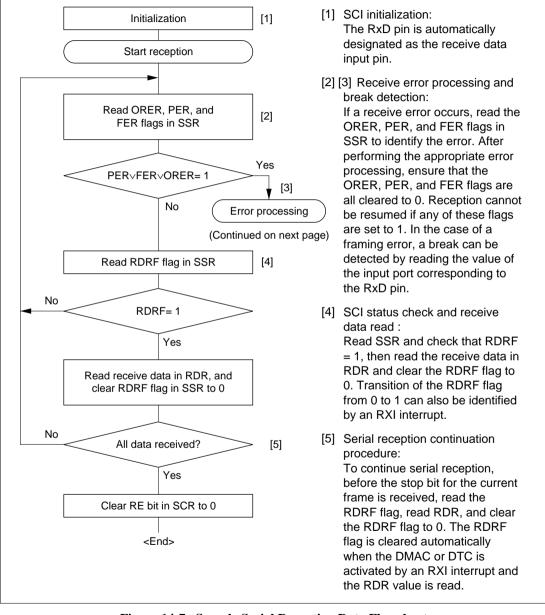


Figure 14-7 Sample Serial Reception Data Flowchart

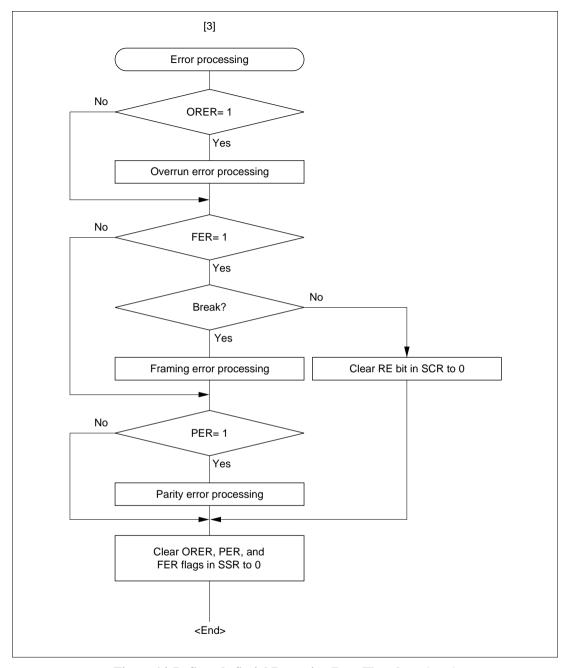


Figure 14-7 Sample Serial Reception Data Flowchart (cont)

In serial reception, the SCI operates as described below.

- [1] The SCI monitors the transmission line, and if a 0 stop bit is detected, performs internal synchronization and starts reception.
- [2] The received data is stored in RSR in LSB-to-MSB order.
- [3] The parity bit and stop bit are received.

After receiving these bits, the SCI carries out the following checks.

[a] Parity check:

The SCI checks whether the number of 1 bits in the receive data agrees with the parity (even or odd) set in the O/\overline{E} bit in SMR.

[b] Stop bit check:

The SCI checks whether the stop bit is 1.

If there are two stop bits, only the first is checked.

[c] Status check:

The SCI checks whether the RDRF flag is 0, indicating that the receive data can be transferred from RSR to RDR.

If all the above checks are passed, the RDRF flag is set to 1, and the receive data is stored in RDR.

If a receive error* is detected in the error check, the operation is as shown in table 14-11.

- Note: * Subsequent receive operations cannot be performed when a receive error has occurred. Also note that the RDRF flag is not set to 1 in reception, and so the error flags must be cleared to 0.
- [4] If the RIE bit in SCR is set to 1 when the RDRF flag changes to 1, a receive data full interrupt (RXI) request is generated.

Also, if the RIE bit in SCR is set to 1 when the ORER, PER, or FER flag changes to 1, a receive error interrupt (ERI) request is generated.

Table 14-11 Receive Errors and Conditions for Occurrence

Receive Error	Abbreviation	Occurrence Condition	Data Transfer	
Overrun error	ORER	When the next data reception is completed while the RDRF flag in SSR is set to 1	Receive data is not transferred from RSR to RDR.	
Framing error	FER	When the stop bit is 0	Receive data is transferred from RSR to RDR.	
Parity error	PER	When the received data differs from the parity (even or odd) set in SMR	Receive data is transferred from RSR to RDR.	

Figure 14-8 shows an example of the operation for reception in asynchronous mode.

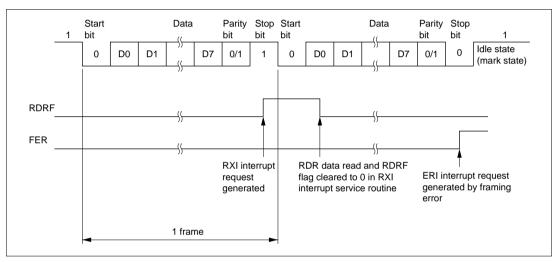


Figure 14-8 Example of SCI Operation in Reception (Example with 8-Bit Data, Parity, One Stop Bit)

14.3.3 Multiprocessor Communication Function

The multiprocessor communication function performs serial communication using the multiprocessor format, in which a multiprocessor bit is added to the transfer data, in asynchronous mode. Use of this function enables data transfer to be performed among a number of processors sharing transmission lines.

When multiprocessor communication is carried out, each receiving station is addressed by a unique ID code.

The serial communication cycle consists of two component cycles: an ID transmission cycle which specifies the receiving station, and a data transmission cycle. The multiprocessor bit is used to differentiate between the ID transmission cycle and the data transmission cycle.

The transmitting station first sends the ID of the receiving station with which it wants to perform serial communication as data with a 1 multiprocessor bit added. It then sends transmit data as data with a 0 multiprocessor bit added.

The receiving station skips the data until data with a 1 multiprocessor bit is sent.

When data with a 1 multiprocessor bit is received, the receiving station compares that data with its own ID. The station whose ID matches then receives the data sent next. Stations whose ID does not match continue to skip the data until data with a 1 multiprocessor bit is again received. In this way, data communication is carried out among a number of processors.

Figure 14-9 shows an example of inter-processor communication using the multiprocessor format.

Data Transfer Format: There are four data transfer formats.

When the multiprocessor format is specified, the parity bit specification is invalid.

For details, see table 14-10.

Clock: See the section on asynchronous mode.

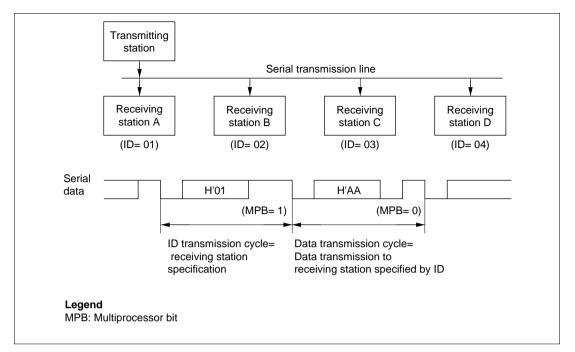


Figure 14-9 Example of Inter-Processor Communication Using Multiprocessor Format (Transmission of Data H'AA to Receiving Station A)

Data Transfer Operations:

Multiprocessor serial data transmission
 Figure 14-10 shows a sample flowchart for multiprocessor serial data transmission.

The following procedure should be used for multiprocessor serial data transmission.

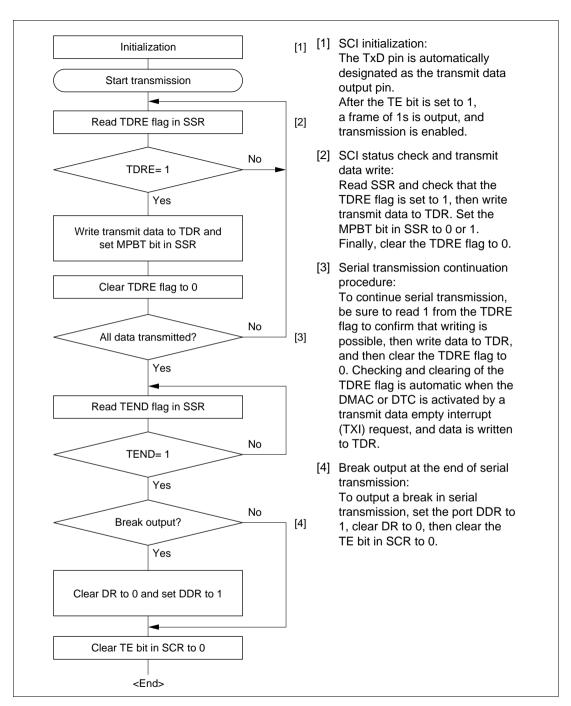


Figure 14-10 Sample Multiprocessor Serial Transmission Flowchart

In serial transmission, the SCI operates as described below.

- [1] The SCI monitors the TDRE flag in SSR, and if is 0, recognizes that data has been written to TDR, and transfers the data from TDR to TSR.
- [2] After transferring data from TDR to TSR, the SCI sets the TDRE flag to 1 and starts transmission.

If the TIE bit is set to 1 at this time, a transmit data empty interrupt (TXI) is generated.

The serial transmit data is sent from the TxD pin in the following order.

[a] Start bit:

One 0-bit is output.

[b] Transmit data:

8-bit or 7-bit data is output in LSB-first order.

[c] Multiprocessor bit

One multiprocessor bit (MPBT value) is output.

[d] Stop bit(s):

One or two 1-bits (stop bits) are output.

[e] Mark state:

1 is output continuously until the start bit that starts the next transmission is sent.

[3] The SCI checks the TDRE flag at the timing for sending the stop bit.

If the TDRE flag is cleared to 0, data is transferred from TDR to TSR, the stop bit is sent, and then serial transmission of the next frame is started.

If the TDRE flag is set to 1, the TEND flag in SSR is set to 1, the stop bit is sent, and then the mark state is entered in which 1 is output continuously. If the TEIE bit in SCR is set to 1 at this time, a transmission end interrupt (TEI) request is generated.

Figure 14-11 shows an example of SCI operation for transmission using the multiprocessor format.

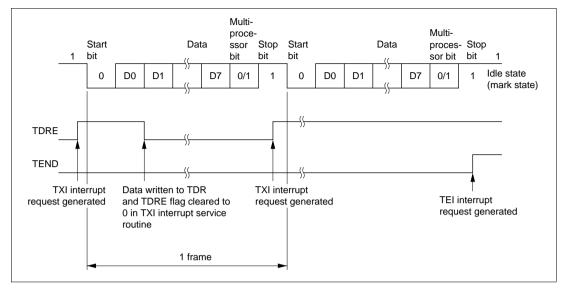


Figure 14-11 Example of SCI Operation in Transmission (Example with 8-Bit Data, Multiprocessor Bit, One Stop Bit)

Multiprocessor serial data reception
 Figure 14-12 shows a sample flowchart for multiprocessor serial reception.

The following procedure should be used for multiprocessor serial data reception.

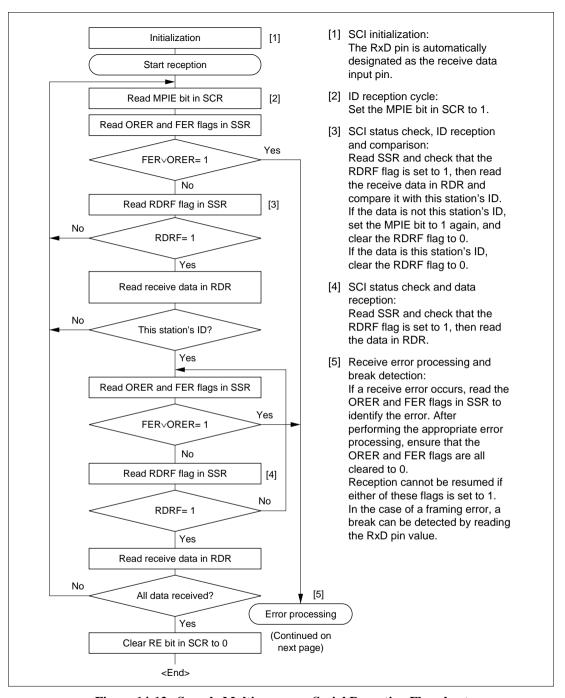


Figure 14-12 Sample Multiprocessor Serial Reception Flowchart

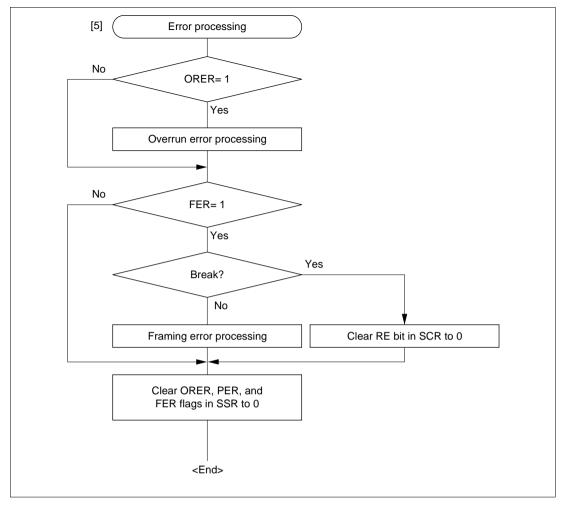


Figure 14-12 Sample Multiprocessor Serial Reception Flowchart (cont)

Figure 14-13 shows an example of SCI operation for multiprocessor format reception.

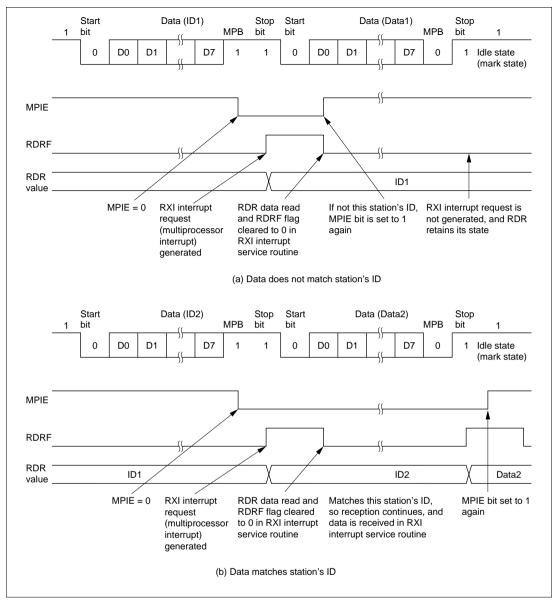


Figure 14-13 Example of SCI Operation in Reception (Example with 8-Bit Data, Multiprocessor Bit, One Stop Bit)

14.3.4 Operation in Clocked Synchronous Mode

In clocked synchronous mode, data is transmitted or received in synchronization with clock pulses, making it suitable for high-speed serial communication.

Inside the SCI, the transmitter and receiver are independent units, enabling full-duplex communication by use of a common clock. Both the transmitter and the receiver also have a double-buffered structure, so that data can be read or written during transmission or reception, enabling continuous data transfer.

Figure 14-14 shows the general format for clocked synchronous serial communication.

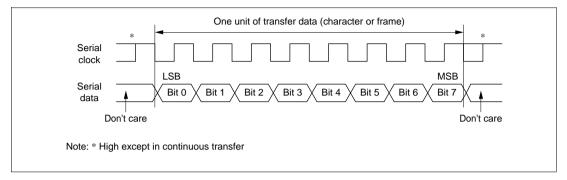


Figure 14-14 Data Format in Synchronous Communication

In clocked synchronous serial communication, data on the transmission line is output from one falling edge of the serial clock to the next. Data confirmation is guaranteed at the rising edge of the serial clock.

In clocked serial communication, one character consists of data output starting with the LSB and ending with the MSB. After the MSB is output, the transmission line holds the MSB state.

In clocked synchronous mode, the SCI receives data in synchronization with the rising edge of the serial clock.

Data Transfer Format: A fixed 8-bit data format is used.

No parity or multiprocessor bits are added.

Clock: Either an internal clock generated by the on-chip baud rate generator or an external serial clock input at the SCK pin can be selected, according to the setting of the C/\overline{A} bit in SMR and the CKE1 and CKE0 bits in SCR. For details of SCI clock source selection, see table 14-9.

When the SCI is operated on an internal clock, the serial clock is output from the SCK pin.

Eight serial clock pulses are output in the transfer of one character, and when no transfer is performed the clock is fixed high. When only receive operations are performed, however, the serial clock is output until an overrun error occurs or the RE bit is cleared to 0. If you want to perform receive operations in units of one character, you should select an external clock as the clock source.

Data Transfer Operations:

SCI initialization (clocked synchronous mode)
 Before transmitting and receiving data, you should first clear the TE and RE bits in SCR to 0,

change the contents of the RDRF, PER, FER, and ORER flags, or the contents of RDR.

When the operating mode, transfer format, etc., is changed, the TE and RE bits must be cleared to 0 before making the change using the following procedure. When the TE bit is cleared to 0, the TDRE flag is set to 1 and TSR is initialized. Note that clearing the RE bit to 0 does not

Figure 14-15 shows a sample SCI initialization flowchart.

then initialize the SCI as described below.

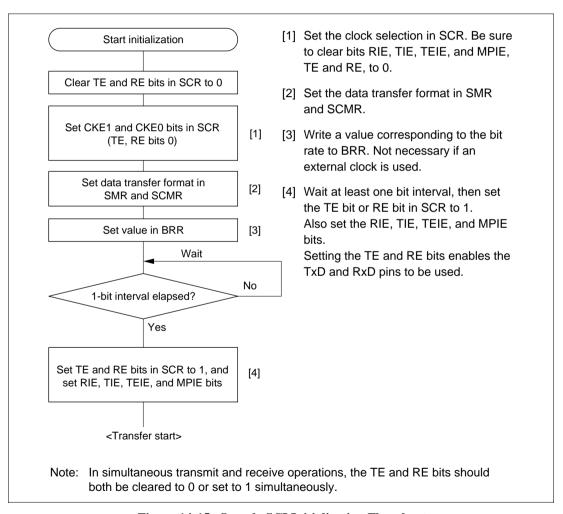


Figure 14-15 Sample SCI Initialization Flowchart

Serial data transmission (clocked synchronous mode)
 Figure 14-16 shows a sample flowchart for serial transmission.

The following procedure should be used for serial data transmission.

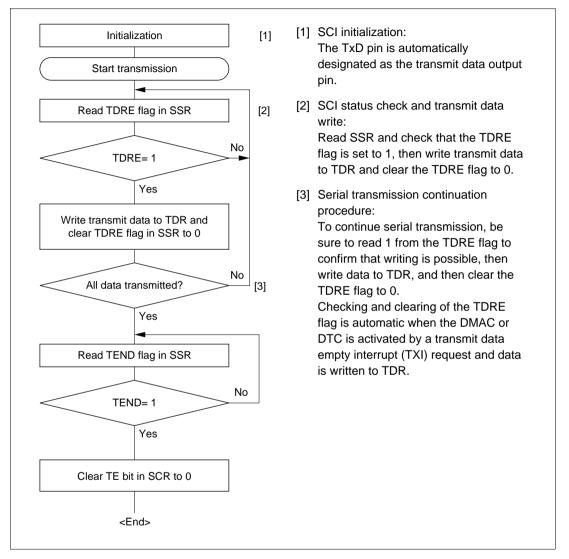


Figure 14-16 Sample Serial Transmission Flowchart

In serial transmission, the SCI operates as described below.

- [1] The SCI monitors the TDRE flag in SSR, and if is 0, recognizes that data has been written to TDR, and transfers the data from TDR to TSR.
- [2] After transferring data from TDR to TSR, the SCI sets the TDRE flag to 1 and starts transmission. If the TIE bit is set to 1 at this time, a transmit data empty interrupt (TXI) is generated.

When clock output mode has been set, the SCI outputs 8 serial clock pulses. When use of an external clock has been specified, data is output synchronized with the input clock.

The serial transmit data is sent from the TxD pin starting with the LSB (bit 0) and ending with the MSB (bit 7).

[3] The SCI checks the TDRE flag at the timing for sending the MSB (bit 7).

If the TDRE flag is cleared to 0, data is transferred from TDR to TSR, and serial transmission of the next frame is started.

If the TDRE flag is set to 1, the TEND flag in SSR is set to 1, the MSB (bit 7) is sent, and the TxD pin maintains its state.

If the TEIE bit in SCR is set to 1 at this time, a TEI interrupt request is generated.

[4] After completion of serial transmission, the SCK pin is fixed.

Figure 14-17 shows an example of SCI operation in transmission.

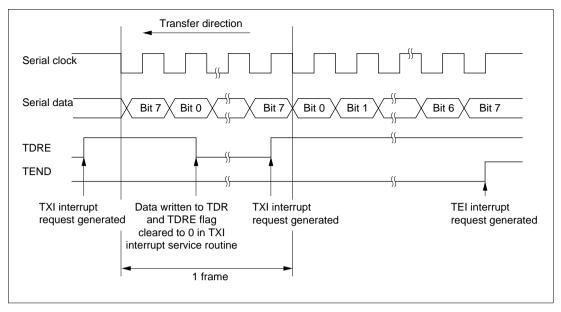


Figure 14-17 Example of SCI Operation in Transmission

Serial data reception (clocked synchronous mode)
 Figure 14-18 shows a sample flowchart for serial reception.

The following procedure should be used for serial data reception.

When changing the operating mode from asynchronous to clocked synchronous, be sure to check that the ORER, PER, and FER flags are all cleared to 0.

The RDRF flag will not be set if the FER or PER flag is set to 1, and neither transmit nor receive operations will be possible.

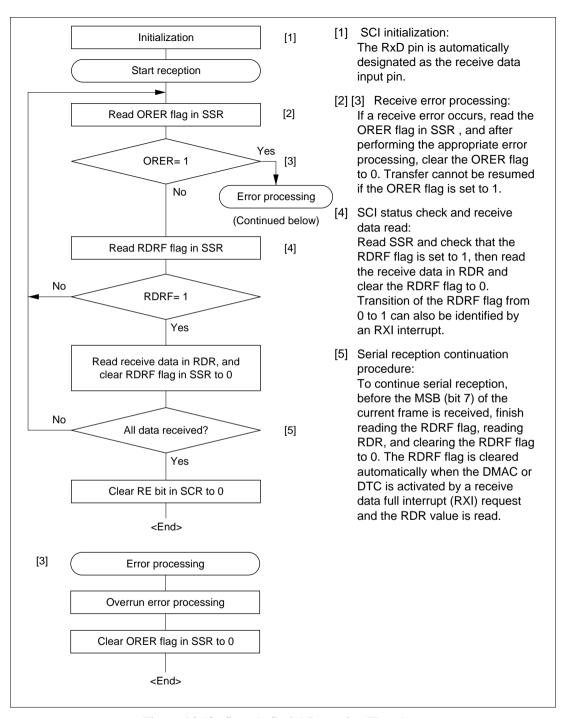


Figure 14-18 Sample Serial Reception Flowchart

In serial reception, the SCI operates as described below.

- [1] The SCI performs internal initialization in synchronization with serial clock input or output.
- [2] The received data is stored in RSR in LSB-to-MSB order.

After reception, the SCI checks whether the RDRF flag is 0 and the receive data can be transferred from RSR to RDR.

If this check is passed, the RDRF flag is set to 1, and the receive data is stored in RDR. If a receive error is detected in the error check, the operation is as shown in table 14-11.

Neither transmit nor receive operations can be performed subsequently when a receive error has been found in the error check.

[3] If the RIE bit in SCR is set to 1 when the RDRF flag changes to 1, a receive data full interrupt (RXI) request is generated.

Also, if the RIE bit in SCR is set to 1 when the ORER flag changes to 1, a receive error interrupt (ERI) request is generated.

Figure 14-19 shows an example of SCI operation in reception.

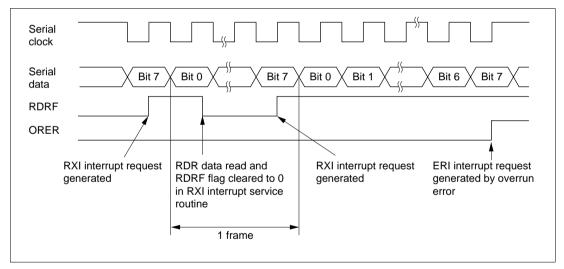


Figure 14-19 Example of SCI Operation in Reception

Simultaneous serial data transmission and reception (clocked synchronous mode)
 Figure 14-20 shows a sample flowchart for simultaneous serial transmit and receive operations.

The following procedure should be used for simultaneous serial data transmit and receive operations.

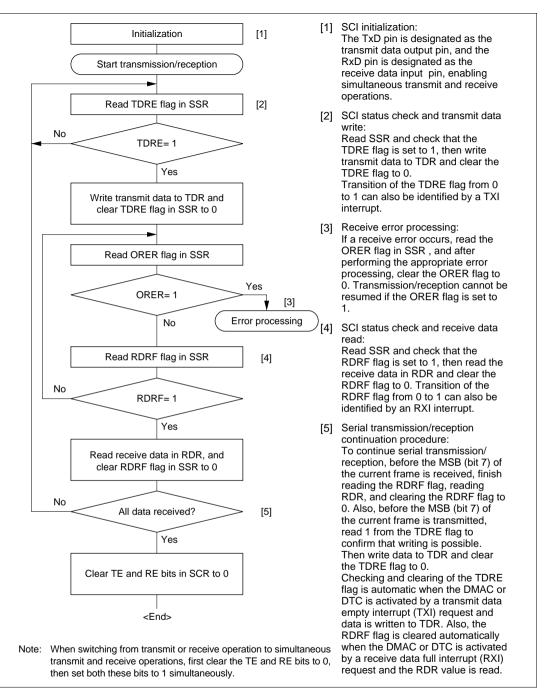


Figure 14-20 Sample Flowchart of Simultaneous Serial Transmit and Receive Operations

14.4 SCI Interrupts

The SCI has four interrupt sources: the transmit-end interrupt (TEI) request, receive-error interrupt (ERI) request, receive-data-full interrupt (RXI) request, and transmit-data-empty interrupt (TXI) request. Table 14-12 shows the interrupt sources and their relative priorities. Individual interrupt sources can be enabled or disabled with the TIE, RIE, and TEIE bits in the SCR. Each kind of interrupt request is sent to the interrupt controller independently.

When the TDRE flag in SSR is set to 1, a TXI interrupt request is generated. When the TEND flag in SSR is set to 1, a TEI interrupt request is generated. A TXI interrupt can activate the DMAC or DTC to perform data transfer. The TDRE flag is cleared to 0 automatically when data transfer is performed by the DMAC or DTC. The DMAC and DTC cannot be activated by a TEI interrupt request.

When the RDRF flag in SSR is set to 1, an RXI interrupt request is generated. When the ORER, PER, or FER flag in SSR is set to 1, an ERI interrupt request is generated. An RXI interrupt can activate the DMAC or DTC to perform data transfer. The RDRF flag is cleared to 0 automatically when data transfer is performed by the DMAC or DTC. The DMAC and DTC cannot be activated by an ERI interrupt request.

Also note that the DMAC cannot be activated by an SCI channel 2 interrupt.

Table 14-12 SCI Interrupt Sources

Channel	Interrupt Source	Description	DTC Activation	DMAC Activation	Priority*
0	ERI	Interrupt due to receive error (ORER, FER, or PER)	Not possible	Not possible	High Å
	RXI	Interrupt due to receive data full state (RDRF)	Possible	Possible	
	TXI	Interrupt due to transmit data empty state (TDRE)	Possible	Possible	_
	TEI	Interrupt due to transmission end (TEND)	Not possible	Not possible	_
1	ERI	Interrupt due to receive error (ORER, FER, or PER)	Not possible	Not possible	_
	RXI	Interrupt due to receive data full state (RDRF)	Possible	Possible	_
	TXI	Interrupt due to transmit data empty state (TDRE)	Possible	Possible	_
	TEI	Interrupt due to transmission end (TEND)	Not possible	Not possible	_
2	ERI	Interrupt due to receive error (ORER, FER, or PER)	Not possible	Not possible	_
	RXI	Interrupt due to receive data full state (RDRF)	Possible	Not possible	_
	TXI	Interrupt due to transmit data empty state (TDRE)	Possible	Not possible	
	TEI	Interrupt due to transmission end (TEND)	Not possible	Not possible	Low

Note: * This table shows the initial state immediately after a reset. Relative priorities among channels can be changed by means of ICR and IPR.

A TEI interrupt is requested when the TEND flag is set to 1 while the TEIE bit is set to 1. The TEND flag is cleared at the same time as the TDRE flag. Consequently, if a TEI interrupt and a TXI interrupt are requested simultaneously, the TXI interrupt may be accepted first, with the result that the TDRE and TEND flags are cleared. Note that the TEI interrupt will not be accepted in this case.

14.5 Usage Notes

The following points should be noted when using the SCI.

Relation between Writes to TDR and the TDRE Flag

The TDRE flag in SSR is a status flag that indicates that transmit data has been transferred from TDR to TSR. When the SCI transfers data from TDR to TSR, the TDRE flag is set to 1.

Data can be written to TDR regardless of the state of the TDRE flag. However, if new data is written to TDR when the TDRE flag is cleared to 0, the data stored in TDR will be lost since it has not yet been transferred to TSR. It is therefore essential to check that the TDRE flag is set to 1 before writing transmit data to TDR.

Operation when Multiple Receive Errors Occur Simultaneously

If a number of receive errors occur at the same time, the state of the status flags in SSR is as shown in table 14-13. If there is an overrun error, data is not transferred from RSR to RDR, and the receive data is lost.

Table 14-13 State of SSR Status Flags and Transfer of Receive Data

	SSR Status Flags			Receive Data Transfer	
RDRF	ORER	FER	PER	RSR to RDR	Receive Error Status
1	1	0	0	Х	Overrun error
0	0	1	0	0	Framing error
0	0	0	1	0	Parity error
1	1	1	0	Х	Overrun error + framing error
1	1	0	1	Х	Overrun error + parity error
0	0	1	1	0	Framing error + parity error
1	1	1	1	Х	Overrun error + framing error + parity error

Notes: O: Receive data is transferred from RSR to RDR.

X: Receive data is not transferred from RSR to RDR.

Break Detection and Processing (Asynchronous Mode Only): When framing error (FER) detection is performed, a break can be detected by reading the RxD pin value directly. In a break, the input from the RxD pin becomes all 0s, and so the FER flag is set, and the parity error flag (PER) may also be set.

Note that, since the SCI continues the receive operation after receiving a break, even if the FER flag is cleared to 0, it will be set to 1 again.

Sending a Break (**Asynchronous Mode Only**): The TxD pin has a dual function as an I/O port whose direction (input or output) is determined by DR and DDR. This can be used to send a break.

Between serial transmission initialization and setting of the TE bit to 1, the mark state is replaced by the value of DR (the pin does not function as the TxD pin until the TE bit is set to 1). Consequently, DDR and DR for the port corresponding to the TxD pin are first set to 1.

To send a break during serial transmission, first clear DR to 0, then clear the TE bit to 0.

When the TE bit is cleared to 0, the transmitter is initialized regardless of the current transmission state, the TxD pin becomes an I/O port, and 0 is output from the TxD pin.

Receive Error Flags and Transmit Operations (Clocked Synchronous Mode Only):

Transmission cannot be started when a receive error flag (ORER, PER, or FER) is set to 1, even if the TDRE flag is cleared to 0. Be sure to clear the receive error flags to 0 before starting transmission.

Note also that receive error flags cannot be cleared to 0 even if the RE bit is cleared to 0.

Receive Data Sampling Timing and Reception Margin in Asynchronous Mode:

In asynchronous mode, the SCI operates on a basic clock with a frequency of 16 times the transfer rate.

In reception, the SCI samples the falling edge of the start bit using the basic clock, and performs internal synchronization. Receive data is latched internally at the rising edge of the 8th pulse of the basic clock. This is illustrated in figure 14-21.

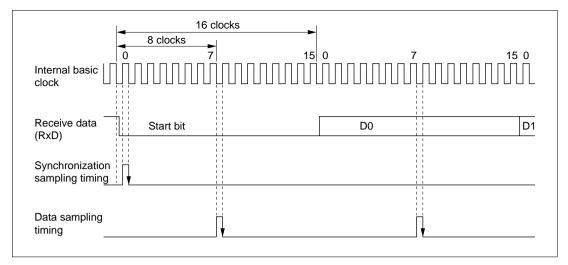


Figure 14-21 Receive Data Sampling Timing in Asynchronous Mode

Thus the reception margin in asynchronous mode is given by formula (1) below.

$$M = \mid (0.5 - \frac{1}{2N}) - (L - 0.5) \ F - \frac{\mid D - 0.5 \mid}{N} (1 + F) \mid \times 100\%$$

... Formula (1)

Where M: Reception margin (%)

N: Ratio of bit rate to clock (N = 16)

D : Clock duty (D = 0 to 1.0) L : Frame length (L = 9 to 12)

F : Absolute value of clock rate deviation

Assuming values of F=0 and D=0.5 in formula (1), a reception margin of 46.875% is given by formula (2) below.

When D = 0.5 and F = 0,

$$M = (0.5 - \frac{1}{2 \times 16}) \times 100\%$$

However, this is only the computed value, and a margin of 20% to 30% should be allowed in system design.

Restrictions on Use of DMAC or DTC

- When an external clock source is used as the serial clock, the transmit clock should not be input until at least 5 ø clock cycles after TDR is updated by the DMAC or DTC. Misoperation may occur if the transmit clock is input within 4 ø clocks after TDR is updated. (Figure 14-22)
- When RDR is read by the DMAC or DTC, be sure to set the activation source to the relevant SCI reception data full interrupt (RXI).

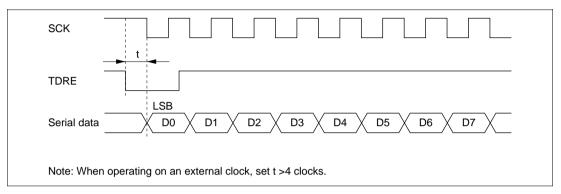


Figure 14-22 Example of Clocked Synchronous Transmission by DTC

Operation before mode transition (for the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390)

Before a mode transition to module stop mode or software standby mode, SCR should be initialized first, then SMR, BRR, and SCMR should be initialized.

Section 15 Smart Card Interface

15.1 Overview

SCI supports an IC card (Smart Card) interface conforming to ISO/IEC 7816-3 (Identification Card) as a serial communication interface extension function.

Switching between the normal serial communication interface and the Smart Card interface is carried out by means of a register setting.

15.1.1 Features

Features of the Smart Card interface supported by the H8S/2357 Series are as follows.

- Asynchronous mode
 - Data length: 8 bits
 - Parity bit generation and checking
 - Transmission of error signal (parity error) in receive mode
 - Error signal detection and automatic data retransmission in transmit mode
 - Direct convention and inverse convention both supported
- On-chip baud rate generator allows any bit rate to be selected
- Three interrupt sources
 - Three interrupt sources (transmit data empty, receive data full, and transmit/receive error) that can issue requests independently
 - The transmit data empty interrupt and receive data full interrupt can activate the DMA controller (DMAC) or data transfer controller (DTC) to execute data transfer

15.1.2 Block Diagram

Figure 15-1 shows a block diagram of the Smart Card interface.

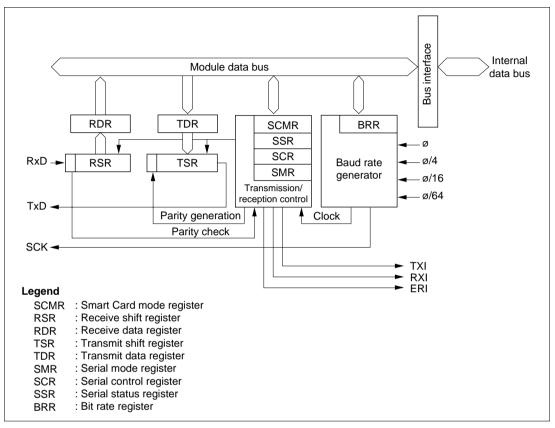


Figure 15-1 Block Diagram of Smart Card Interface

15.1.3 Pin Configuration

Table 15-1 shows the Smart Card interface pin configuration.

Table 15-1 Smart Card Interface Pins

Channel	Pin Name	Symbol	I/O	Function
0	Serial clock pin 0	SCK0	I/O	SCI0 clock input/output
	Receive data pin 0	RxD0	Input	SCI0 receive data input
	Transmit data pin 0	TxD0	Output	SCI0 transmit data output
1	Serial clock pin 1	SCK1	I/O	SCI1 clock input/output
	Receive data pin 1	RxD1	Input	SCI1 receive data input
	Transmit data pin 1	TxD1	Output	SCI1 transmit data output
2	Serial clock pin 2	SCK2	I/O	SCI2 clock input/output
	Receive data pin 2	RxD2	Input	SCI2 receive data input
	Transmit data pin 2	TxD2	Output	SCI2 transmit data output

15.1.4 Register Configuration

Table 15-2 shows the registers used by the Smart Card interface. Details of SMR, BRR, SCR, TDR, RDR, and MSTPCR are the same as for the normal SCI function: see the register descriptions in section 14, Serial Communication Interface.

Table 15-2 Smart Card Interface Registers

Channel	Name	Abbreviation	R/W	Initial Value	Address*1
0	Serial mode register 0	SMR0	R/W	H'00	H'FF78
	Bit rate register 0	BRR0	R/W	H'FF	H'FF79
	Serial control register 0	SCR0	R/W	H'00	H'FF7A
	Transmit data register 0	TDR0	R/W	H'FF	H'FF7B
	Serial status register 0	SSR0	R/(W)*2	H'84	H'FF7C
	Receive data register 0	RDR0	R	H'00	H'FF7D
	Smart card mode register 0	SCMR0	R/W	H'F2	H'FF7E
1	Serial mode register 1	SMR1	R/W	H'00	H'FF80
	Bit rate register 1	BRR1	R/W	H'FF	H'FF81
	Serial control register 1	SCR1	R/W	H'00	H'FF82
	Transmit data register 1	TDR1	R/W	H'FF	H'FF83
	Serial status register 1	SSR1	R/(W)*2	H'84	H'FF84
	Receive data register 1	RDR1	R	H'00	H'FF85
	Smart card mode register 1	SCMR1	R/W	H'F2	H'FF86
2	Serial mode register 2	SMR2	R/W	H'00	H'FF88
	Bit rate register 2	BRR2	R/W	H'FF	H'FF89
	Serial control register 2	SCR2	R/W	H'00	H'FF8A
	Transmit data register 2	TDR2	R/W	H'FF	H'FF8B
	Serial status register 2	SSR2	R/(W)*2	H'84	H'FF8C
	Receive data register 2	RDR2	R	H'00	H'FF8D
	Smart card mode register 2	SCMR2	R/W	H'F2	H'FF8E
All	Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address.

^{2.} Can only be written with 0 for flag clearing.

15.2 Register Descriptions

Registers added with the Smart Card interface and bits for which the function changes are described here.

15.2.1 Smart Card Mode Register (SCMR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	SDIR	SINV	_	SMIF
Initial value	e:	1	1	1	1	0	0	1	0
R/W	:	_	_	_	_	R/W	R/W	_	R/W

SCMR is an 8-bit readable/writable register that selects the Smart Card interface function.

SCMR is initialized to H'F2 by a reset, and in standby mode or module stop mode.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 1.

Bit 3—Smart Card Data Transfer Direction (SDIR): Selects the serial/parallel conversion format.

Bit 3 SDIR	Description	
0	TDR contents are transmitted LSB-first	(Initial value)
	Receive data is stored in RDR LSB-first	
1	TDR contents are transmitted MSB-first	
	Receive data is stored in RDR MSB-first	

Bit 2—Smart Card Data Invert (SINV): Specifies inversion of the data logic level. This function is used together with the SDIR bit for communication with an inverse convention card. The SINV bit does not affect the logic level of the parity bit. For parity-related setting procedures, see section 15.3.4, Register Settings.

Bit 2 SINV	Description	
0	TDR contents are transmitted as they are	(Initial value)
	Receive data is stored as it is in RDR	
1	TDR contents are inverted before being transmitted	
	Receive data is stored in inverted form in RDR	

Bit 1—Reserved: This bit cannot be modified and is always read as 1.

Bit 0—Smart Card Interface Mode Select (SMIF): Enables or disables the Smart Card interface function.

Bit 0		
SMIF	Description	
0	Smart Card interface function is disabled	(Initial value)
1	Smart Card interface function is enabled	

15.2.2 Serial Status Register (SSR)

Bit	:	7	6	5	4	3	2	1	0
		TDRE	RDRF	ORER	ERS	PER	TEND	MPB	MPBT
Initial value:		1	0	0	0	0	1	0	0
R/W	:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W

Note: * Only 0 can be written to bits 7 to 3, to clear these flags.

Bit 4 of SSR has a different function in Smart Card interface mode. Coupled with this, the setting conditions for bit 2, TEND, are also different.

Bits 7 to 5—Operate in the same way as for the normal SCI. For details, see section 14.2.7, Serial Status Register (SSR).

Bit 4—Error Signal Status (ERS): In Smart Card interface mode, bit 4 indicates the status of the error signal sent back from the receiving end in transmission. Framing errors are not detected in Smart Card interface mode.

Bit 4 ERS	Description	
0	[Clearing condition]	(Initial value)
	 Upon reset, and in standby mode or module stop mode 	
	 When 0 is written to ERS after reading ERS = 1 	
1	[Setting condition]	-
	When the low level of the error signal is sampled	

Note: Clearing the TE bit in SCR to 0 does not affect the ERS flag, which retains its previous state.

Bits 3 to 0—Operate in the same way as for the normal SCI. For details, see section 14.2.7, Serial Status Register (SSR).

However, the setting conditions for the TEND bit, are as shown below.

Bit 2 TEND	Description						
0	[Clearing conditions] (Initial value)						
	 When 0 is written to TDRE after reading TDRE = 1 						
	 When the DMAC or DTC is activated by a TXI interrupt and write data to TDR 						
1	[Setting conditions]						
	 Upon reset, and in standby mode or module stop mode 						
	 When the TE bit in SCR is 0 and the ERS bit is also 0 						
	When TDRE = 1 and ERS = 0 (normal transmission) 2.5 etu after transmission of a						
	1-byte serial character when GM = 0						
	 When TDRE = 1 and ERS = 0 (normal transmission) 1.0 etu after transmission of a 1-byte serial character when GM = 1 						

Note: etu: Elementary Time Unit (time for transfer of 1 bit)

15.2.3 Serial Mode Register (SMR)

D:(A

Bit	:	7	6	5	4	3	2	1	0
		GM	CHR	PE	O/E	STOP	MP	CKS1	CKS0
Initial va	ılue :	0	0	0	0	0	0	0	0
Set valu	e* :	GM	0	1	O/Ē	1	0	CKS1	CKS0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Note: *When the smart card interface is used, be sure to make the 0 or 1 setting shown for bits 6, 5, 3, and 2.

The function of bit 7 of SMR changes in smart card interface mode.

Bit 7—GSM Mode (GM): Sets the smart card interface function to GSM mode.

This bit is cleared to 0 when the normal smart card interface is used. In GSM mode, this bit is set to 1, the timing of setting of the TEND flag that indicates transmission completion is advanced and clock output control mode addition is performed. The contents of the clock output control mode addition are specified by bits 1 and 0 of the serial control register (SCR).

Bit 7 GM	Description						
0	Normal smart card interface mode operation (Initial value)						
	 TEND flag generation 12.5 etu after beginning of start bit 						
	Clock output ON/OFF control only						
1	GSM mode smart card interface mode operation						
	 TEND flag generation 11.0 etu after beginning of start bit 						
	 High/low fixing control possible in addition to clock output ON/OFF control (set by SCR) 						

Note: etu: Elementary time unit (time for transfer of 1 bit)

Bits 6 to 0—Operate in the same way as for the normal SCI.

For details, see section 14.2.5, Serial Mode Register (SMR).

15.2.4 Serial Control Register (SCR)

Bit	:	7	6	5	4	3	2	1	0
		TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

In smart card interface mode, the function of bits 1 and 0 of SCR changes when bit 7 of the serial mode register (SMR) is set to 1.

Bits 7 to 2—Operate in the same way as for the normal SCI.

For details, see section 14.2.6, Serial Control Register (SCR).

Bits 1 and 0—Clock Enable 1 and 0 (CKE1, CKE0): These bits are used to select the SCI clock source and enable or disable clock output from the SCK pin.

In smart card interface mode, in addition to the normal switching between clock output enabling and disabling, the clock output can be specified as to be fixed high or low.

SCMR	SMR	SMR SCR Setting						
SMIF	C/A, GM	CKE1	CKE0	SCK Pin Function				
0	See the SC	CI .						
1	0	0	0	Operates as port I/O pin				
1	0	0	1	Outputs clock as SCK output pin				
1	1	0	0	Operates as SCK output pin, with output fixed low				
1	1	0	1	Outputs clock as SCK output pin				
1	1	1	0	Operates as SCK output pin, with output fixed high				
1	1	1	1	Outputs clock as SCK output pin				

15.3 Operation

15.3.1 Overview

The main functions of the Smart Card interface are as follows.

- One frame consists of 8-bit data plus a parity bit.
- In transmission, a guard time of at least 2 etu (Elementary Time Unit: the time for transfer of one bit) is left between the end of the parity bit and the start of the next frame.
- If a parity error is detected during reception, a low error signal level is output for one etu period, 10.5 etu after the start bit.
- If the error signal is sampled during transmission, the same data is transmitted automatically after the elapse of 2 etu or longer.
- Only asynchronous communication is supported; there is no clocked synchronous communication function.

15.3.2 Pin Connections

Figure 15-2 shows a schematic diagram of Smart Card interface related pin connections.

In communication with an IC card, since both transmission and reception are carried out on a single data transmission line, the TxD pin and RxD pin should be connected with the LSI pin. The data transmission line should be pulled up to the $V_{\rm CC}$ power supply with a resistor.

When the clock generated on the Smart Card interface is used by an IC card, the SCK pin output is input to the CLK pin of the IC card. No connection is needed if the IC card uses an internal clock.

LSI port output is used as the reset signal.

Other pins must normally be connected to the power supply or ground.

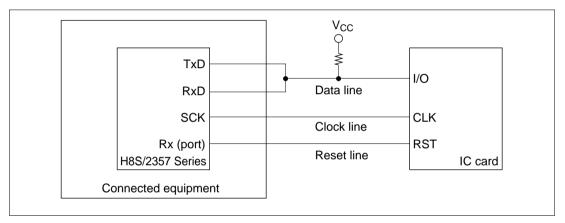


Figure 15-2 Schematic Diagram of Smart Card Interface Pin Connections

Note: If an IC card is not connected, and the TE and RE bits are both set to 1, closed transmission/reception is possible, enabling self-diagnosis to be carried out.

15.3.3 Data Format

Figure 15-3 shows the Smart Card interface data format. In reception in this mode, a parity check is carried out on each frame, and if an error is detected an error signal is sent back to the transmitting end, and retransmission of the data is requested. If an error signal is sampled during transmission, the same data is retransmitted.

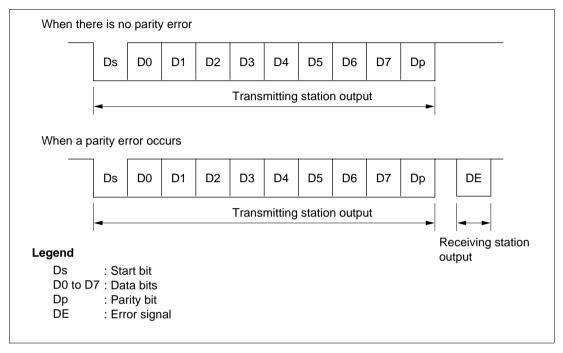


Figure 15-3 Smart Card Interface Data Format

The operation sequence is as follows.

- [1] When the data line is not in use it is in the high-impedance state, and is fixed high with a pull-up resistor.
- [2] The transmitting station starts transfer of one frame of data. The data frame starts with a start bit (Ds, low-level), followed by 8 data bits (D0 to D7) and a parity bit (Dp).
- [3] With the Smart Card interface, the data line then returns to the high-impedance state. The data line is pulled high with a pull-up resistor.
- [4] The receiving station carries out a parity check.
 - If there is no parity error and the data is received normally, the receiving station waits for reception of the next data.
 - If a parity error occurs, however, the receiving station outputs an error signal (DE, low-level) to request retransmission of the data. After outputting the error signal for the prescribed length of time, the receiving station places the signal line in the high-impedance state again. The signal line is pulled high again by a pull-up resistor.
- [5] If the transmitting station does not receive an error signal, it proceeds to transmit the next data frame.
 - If it does receive an error signal, however, it returns to step [2] and retransmits the erroneous data.

15.3.4 Register Settings

Table 15-3 shows a bit map of the registers used by the smart card interface.

Bits indicated as 0 or 1 must be set to the value shown. The setting of other bits is described below.

Table 15-3 Smart Card Interface Register Settings

	Bit							
Register	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
SMR	GM	0	1	O/Ē	1	0	CKS1	CKS0
BRR	BRR7	BRR6	BRR5	BRR4	BRR3	BRR2	BRR1	BRR0
SCR	TIE	RIE	TE	RE	0	0	CKE1*	CKE0
TDR	TDR7	TDR6	TDR5	TDR4	TDR3	TDR2	TDR1	TDR0
SSR	TDRE	RDRF	ORER	ERS	PER	TEND	0	0
RDR	RDR7	RDR6	RDR5	RDR4	RDR3	RDR2	RDR1	RDR0
SCMR	_	_	_	_	SDIR	SINV	_	SMIF

Notes: —: Unused bit.

SMR Setting: The GM bit is cleared to 0 in normal smart card interface mode, and set to 1 in GSM mode. The O/\overline{E} bit is cleared to 0 if the IC card is of the direct convention type, and set to 1 if of the inverse convention type.

Bits CKS1 and CKS0 select the clock source of the on-chip baud rate generator. See section 15.3.5, Clock.

BRR Setting: BRR is used to set the bit rate. See section 15.3.5, Clock, for the method of calculating the value to be set.

SCR Setting: The function of the TIE, RIE, TE, and RE bits is the same as for the normal SCI. For details, see section 14, Serial Communication Interface.

Bits CKE1 and CKE0 specify the clock output. When the GM bit in SMR is cleared to 0, set these bits to B'00 if a clock is not to be output, or to B'01 if a clock is to be output. When the GM bit in SMR is set to 1, clock output is performed. The clock output can also be fixed high or low.

^{*:} The CKE1 bit must be cleared to 0 when the GM bit in SMR is cleared to 0.

Smart Card Mode Register (SCMR) Setting:

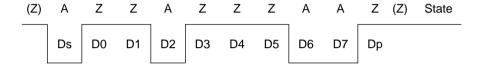
The SDIR bit is cleared to 0 if the IC card is of the direct convention type, and set to 1 if of the inverse convention type.

The SINV bit is cleared to 0 if the IC card is of the direct convention type, and set to 1 if of the inverse convention type.

The SMIF bit is set to 1 in the case of the Smart Card interface.

Examples of register settings and the waveform of the start character are shown below for the two types of IC card (direct convention and inverse convention).

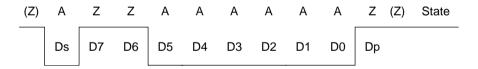
• Direct convention (SDIR = SINV = $O/\overline{E} = 0$)



With the direct convention type, the logic 1 level corresponds to state Z and the logic 0 level to state A, and transfer is performed in LSB-first order. The start character data above is H'3B.

The parity bit is 1 since even parity is stipulated for the Smart Card.

• Inverse convention (SDIR = SINV = $O/\overline{E} = 1$)



With the inverse convention type, the logic 1 level corresponds to state A and the logic 0 level to state Z, and transfer is performed in MSB-first order. The start character data above is H'3F.

The parity bit is 0, corresponding to state Z, since even parity is stipulated for the Smart Card.

With the H8S/2357 Series, inversion specified by the SINV bit applies only to the data bits, D7 to D0. For parity bit inversion, the O/\overline{E} bit in SMR is set to odd parity mode (the same applies to both transmission and reception).

15.3.5 Clock

Only an internal clock generated by the on-chip baud rate generator can be used as the transmit/receive clock for the smart card interface. The bit rate is set with BRR and the CKS1 and CKS0 bits in SMR. The formula for calculating the bit rate is as shown below. Table 15-5 shows some sample bit rates.

If clock output is selected by setting CKE0 to 1, a clock with a frequency of 372 times the bit rate is output from the SCK pin.

$$B = \frac{\emptyset}{1488 \times 2^{2n-1} \times (N+1)} \times 10^{6}$$

Where: N = Value set in BRR (0 N 255)

B = Bit rate (bit/s)

 \emptyset = Operating frequency (MHz)

n = See table 15-4

Table 15-4 Correspondence between n and CKS1, CKS0

n	CKS1	CKS0
0	0	0
1	_	1
2	1	0
3	_	1

Table 15-5 Examples of Bit Rate B (bit/s) for Various BRR Settings (When n = 0)

	ø (MHz)								
N	10.00	10.714	13.00	14.285	16.00	18.00	20.00		
0	13441	14400	17473	19200	21505	24194	26882		
1	6720	7200	8737	9600	10753	12097	13441		
2	4480	4800	5824	6400	7168	8065	8961		

Note: Bit rates are rounded to the nearest whole number.

The method of calculating the value to be set in the bit rate register (BRR) from the operating frequency and bit rate, on the other hand, is shown below. N is an integer, 0 N 255, and the smaller error is specified.

$$N = \frac{\emptyset}{1488 \times 2^{2n-1} \times B} \times 10^6 - 1$$

Table 15-6 Examples of BRR Settings for Bit Rate B (bit/s) (When n = 0)

ø	M	Hz)

	7	7.1424		10.00	1	0.7136		13.00	1	4.2848		16.00		18.00	- :	20.00
bit/s	N	Error	N	Error	N	Error	N	Error	N	Error	N	Error	N	Error	N	Error
9600	0	0.00	1	30	1	25	1	8.99	1	0.00	1	12.01	2	15.99	2	6.60

Table 15-7 Maximum Bit Rate at Various Frequencies (Smart Card Interface Mode)

ø (MHz)	Maximum Bit Rate (bit/s)	N	n
7.1424	9600	0	0
10.00	13441	0	0
10.7136	14400	0	0
13.00	17473	0	0
14.2848	19200	0	0
16.00	21505	0	0
18.00	24194	0	0
20.00	26882	0	0

The bit rate error is given by the following formula:

Error (%) = (
$$\frac{\emptyset}{1488 \times 2^{2n-1} \times B \times (N+1)} \times 10^6 - 1) \times 100$$

15.3.6 Data Transfer Operations

Initialization: Before transmitting and receiving data, initialize the SCI as described below. Initialization is also necessary when switching from transmit mode to receive mode, or vice versa.

- [1] Clear the TE and RE bits in SCR to 0.
- [2] Clear the error flags ERS, PER, and ORER in SSR to 0.
- [3] Set the O/\overline{E} bit and CKS1 and CKS0 bits in SMR. Clear the C/\overline{A} , CHR, and MP bits to 0, and set the STOP and PE bits to 1.
- [4] Set the SMIF, SDIR, and SINV bits in SCMR.

 When the SMIF bit is set to 1, the TxD and RxD pins are both switched from ports to SCI pins, and are placed in the high-impedance state.
- [5] Set the value corresponding to the bit rate in BRR.
- [6] Set the CKE0 bit in SCR. Clear the TIE, RIE, TE, RE, MPIE, TEIE and CKE1 bits to 0. If the CKE0 bit is set to 1, the clock is output from the SCK pin.
- [7] Wait at least one bit interval, then set the TIE, RIE, TE, and RE bits in SCR. Do not set the TE bit and RE bit at the same time, except for self-diagnosis.

Serial Data Transmission: As data transmission in smart card mode involves error signal sampling and retransmission processing, the processing procedure is different from that for the normal SCI. Figure 15-4 shows a flowchart for transmitting, and figure 15-5 shows the relation between a transmit operation and the internal registers.

- [1] Perform Smart Card interface mode initialization as described above in Initialization.
- [2] Check that the ERS error flag in SSR is cleared to 0.
- [3] Repeat steps [2] and [3] until it can be confirmed that the TEND flag in SSR is set to 1.
- [4] Write the transmit data to TDR, clear the TDRE flag to 0, and perform the transmit operation. The TEND flag is cleared to 0.
- [5] When transmitting data continuously, go back to step [2].
- [6] To end transmission, clear the TE bit to 0.

With the above processing, interrupt servicing or data transfer by the DMAC or DTC is possible.

If transmission ends and the TEND flag is set to 1 while the TIE bit is set to 1 and interrupt requests are enabled, a transmit data empty interrupt (TXI) request will be generated. If an error occurs in transmission and the ERS flag is set to 1 while the RIE bit is set to 1 and interrupt requests are enabled, a transfer error interrupt (ERI) request will be generated.

The timing for setting the TEND flag depends on the value of the GM bit in SMR. The TEND flag set timing is shown in figure 15-6.

If the DMAC or DTC is activated by a TXI request, the number of bytes set in the DMAC or DTC can be transmitted automatically, including automatic retransmission.

For details, see Interrupt Operations and Data Transfer Operation by DMAC or DTC below.

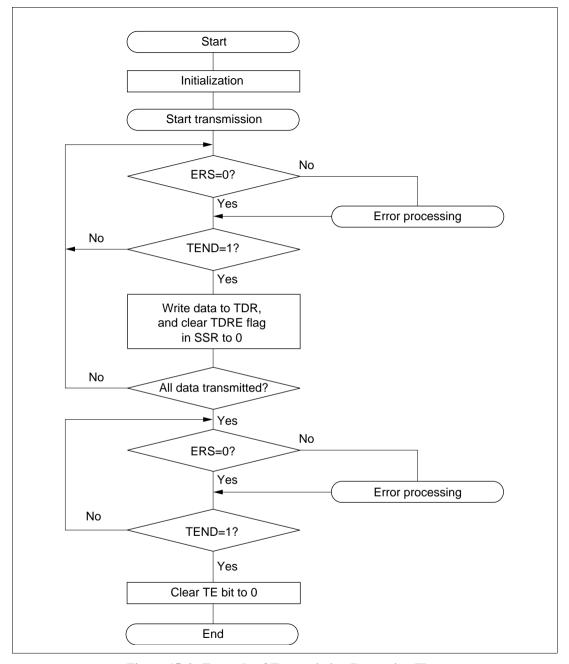


Figure 15-4 Example of Transmission Processing Flow

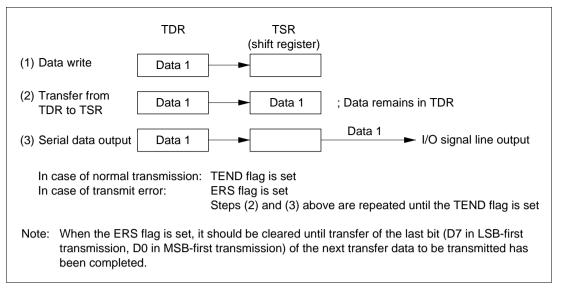


Figure 15-5 Relation Between Transmit Operation and Internal Registers

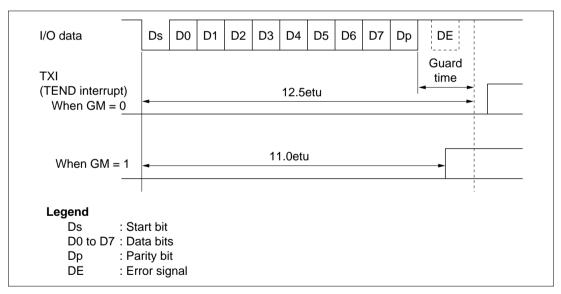


Figure 15-6 TEND Flag Generation Timing in Transmission Operation

Serial Data Reception: Data reception in Smart Card mode uses the same processing procedure as for the normal SCI. Figure 15-7 shows an example of the transmission processing flow.

- [1] Perform Smart Card interface mode initialization as described above in Initialization.
- [2] Check that the ORER flag and PER flag in SSR are cleared to 0. If either is set, perform the appropriate receive error processing, then clear both the ORER and the PER flag to 0.
- [3] Repeat steps [2] and [3] until it can be confirmed that the RDRF flag is set to 1.
- [4] Read the receive data from RDR.
- [5] When receiving data continuously, clear the RDRF flag to 0 and go back to step [2].
- [6] To end reception, clear the RE bit to 0.

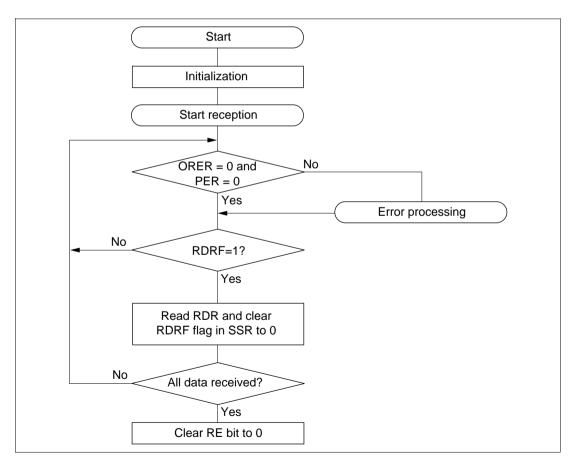


Figure 15-7 Example of Reception Processing Flow

With the above processing, interrupt servicing or data transfer by the DMAC or DTC is possible.

If reception ends and the RDRF flag is set to 1 while the RIE bit is set to 1 and interrupt requests are enabled, a receive data full interrupt (RXI) request will be generated. If an error occurs in reception and either the ORER flag or the PER flag is set to 1, a transfer error interrupt (ERI) request will be generated.

If the DMAC or DTC is activated by an RXI request, the receive data in which the error occurred is skipped, and only the number of bytes of receive data set in the DMAC or DTC are transferred.

For details, see Interrupt Operation and Data Transfer Operation by DMAC or DTC below.

If a parity error occurs during reception and the PER is set to 1, the received data is still transferred to RDR, and therefore this data can be read.

Mode Switching Operation: When switching from receive mode to transmit mode, first confirm that the receive operation has been completed, then start from initialization, clearing RE bit to 0 and setting TE bit to 1. The RDRF flag or the PER and ORER flags can be used to check that the receive operation has been completed.

When switching from transmit mode to receive mode, first confirm that the transmit operation has been completed, then start from initialization, clearing TE bit to 0 and setting RE bit to 1. The TEND flag can be used to check that the transmit operation has been completed.

Fixing Clock Output Level: When the GSM bit in SMR is set to 1, the clock output level can be fixed with bits CKE1 and CKE0 in SCR. At this time, the minimum clock pulse width can be made the specified width.

Figure 15-8 shows the timing for fixing the clock output level. In this example, GSM is set to 1, CKE1 is cleared to 0, and the CKE0 bit is controlled.

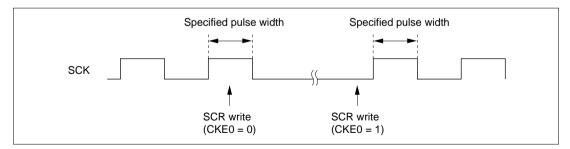


Figure 15-8 Timing for Fixing Clock Output Level

Interrupt Operation: There are three interrupt sources in smart card interface mode: transmit data empty interrupt (TXI) requests, transfer error interrupt (ERI) requests, and receive data full interrupt (RXI) requests. The transmit end interrupt (TEI) request is not used in this mode.

When the TEND flag in SSR is set to 1, a TXI interrupt request is generated.

When the RDRF flag in SSR is set to 1, an RXI interrupt request is generated.

When any of flags ORER, PER, and ERS in SSR is set to 1, an ERI interrupt request is generated. The relationship between the operating states and interrupt sources is shown in table 15-8.

Table 15-8 Smart Card Mode Operating States and Interrupt Sources

Operating	State	Flag	Enable Bit	Interrupt Source	DMAC Activation	DTC Activation
Transmit Mode	Normal operation	TEND	TIE	TXI	Possible	Possible
	Error	ERS	RIE	ERI	Not possible	Not possible
Receive Mode	Normal operation	RDRF	RIE	RXI	Possible	Possible
	Error	PER, ORER	RIE	ERI	Not possible	Not possible

Data Transfer Operation by DMAC or DTC: In smart card mode, as with the normal SCI, transfer can be carried out using the DMAC or DTC. In a transmit operation, the TDRE flag is also set to 1 at the same time as the TEND flag in SSR, and a TXI interrupt is generated. If the TXI request is designated beforehand as a DMAC or DTC activation source, the DMAC or DTC will be activated by the TXI request, and transfer of the transmit data will be carried out. The TDRE and TEND flags are automatically cleared to 0 when data transfer is performed by the DMAC or DTC. In the event of an error, the SCI retransmits the same data automatically. The TEND flag remains cleared to 0 during this time, and the DMAC is not activated. Thus, the number of bytes specified by the SCI and DMAC are transmitted automatically even in retransmission following an error. However, the ERS flag is not cleared automatically when an error occurs, and so the RIE bit should be set to 1 beforehand so that an ERI request will be generated in the event of an error, and the ERS flag will be cleared.

When performing transfer using the DMAC or DTC, it is essential to set and enable the DMAC or DTC before carrying out SCI setting. For details of the DMAC and DTC setting procedures, see section 7, DMA Controller (DMAC), and section 8, Data Transfer Controller (DTC).

In a receive operation, an RXI interrupt request is generated when the RDRF flag in SSR is set to 1. If the RXI request is designated beforehand as a DMAC or DTC activation source, the DMAC or DTC will be activated by the RXI request, and transfer of the receive data will be carried out. The RDRF flag is cleared to 0 automatically when data transfer is performed by the DMAC or DTC. If an error occurs, an error flag is set but the RDRF flag is not. Consequently, the DMAC or DTC is not activated, but instead, an ERI interrupt request is sent to the CPU. Therefore, the error flag should be cleared.

15.3.7 Operation in GSM Mode

Switching the Mode: When switching between smart card interface mode and software standby mode, the following switching procedure should be followed in order to maintain the clock duty.

- When changing from smart card interface mode to software standby mode
- [1] Set the data register (DR) and data direction register (DDR) corresponding to the SCK pin to the value for the fixed output state in software standby mode.
- [2] Write 0 to the TE bit and RE bit in the serial control register (SCR) to halt transmit/receive operation. At the same time, set the CKE1 bit to the value for the fixed output state in software standby mode.
- [3] Write 0 to the CKE0 bit in SCR to halt the clock.
- [4] Wait for one serial clock period.

 During this interval, clock output is fixed at the specified level, with the duty preserved.
- [5] Write H'00 to SMR and SCMR.
- [6] Make the transition to the software standby state.
- When returning to smart card interface mode from software standby mode
- [7] Exit the software standby state.
- [8] Set the CKE1 bit in SCR to the value for the fixed output state (current SCK pin state) when software standby mode is initiated.
- [9] Set smart card interface mode and output the clock. Signal generation is started with the normal duty.

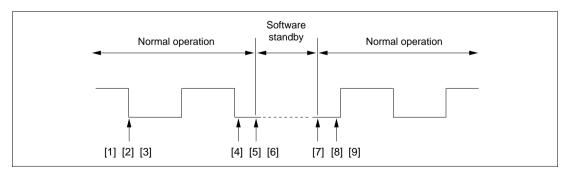


Figure 15-9 Clock Halt and Restart Procedure

Powering On: To secure the clock duty from power-on, the following switching procedure should be followed.

- [1] The initial state is port input and high impedance. Use a pull-up resistor or pull-down resistor to fix the potential.
- [2] Fix the SCK pin to the specified output level with the CKE1 bit in SCR.
- [3] Set SMR and SCMR, and switch to smart card mode operation.
- [4] Set the CKE0 bit in SCR to 1 to start clock output.

15.4 Usage Notes

The following points should be noted when using the SCI as a Smart Card interface.

Receive Data Sampling Timing and Reception Margin in Smart Card Interface Mode: In Smart Card Interface mode, the SCI operates on a basic clock with a frequency of 372 times the transfer rate.

In reception, the SCI samples the falling edge of the start bit using the basic clock, and performs internal synchronization. Receive data is latched internally at the rising edge of the 186th pulse of the basic clock. This is illustrated in figure 15-10.

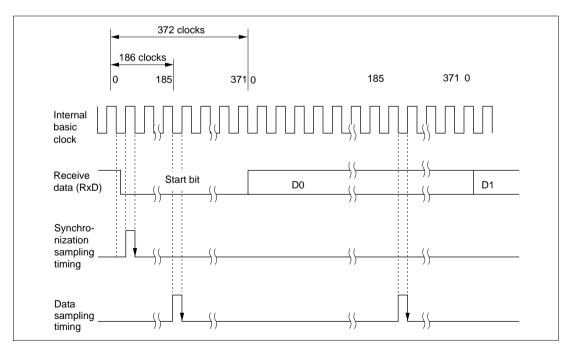


Figure 15-10 Receive Data Sampling Timing in Smart Card Mode

Thus the reception margin in asynchronous mode is given by the following formula.

$$M = \left| \; (0.5 - \frac{1}{2N}) - (L - 0.5) \; F - \frac{\left| \; D - 0.5 \; \right|}{N} (1 + F) \; \right| \times 100\%$$

Where M: Reception margin (%)

N: Ratio of bit rate to clock (N = 372)

D: Clock duty (D = 0 to 1.0)

L: Frame length (L = 10)

F: Absolute value of clock frequency deviation

Assuming values of F = 0 and D = 0.5 in the above formula, the reception margin formula is as follows.

When D = 0.5 and F = 0,
M =
$$(0.5 - 1/2 \times 372) \times 100\%$$

= 49.866%

Retransfer Operations: Retransfer operations are performed by the SCI in receive mode and transmit mode as described below.

- Retransfer operation when SCI is in receive mode
 Figure 15-11 illustrates the retransfer operation when the SCI is in receive mode.
- [1] If an error is found when the received parity bit is checked, the PER bit in SSR is automatically set to 1. If the RIE bit in SCR is enabled at this time, an ERI interrupt request is generated. The PER bit in SSR should be kept cleared to 0 until the next parity bit is sampled.
- [2] The RDRF bit in SSR is not set for a frame in which an error has occurred.
- [3] If no error is found when the received parity bit is checked, the PER bit in SSR is not set to 1.
- [4] If no error is found when the received parity bit is checked, the receive operation is judged to have been completed normally, and the RDRF flag in SSR is automatically set to 1. If the RIE bit in SCR is enabled at this time, an RXI interrupt request is generated.
 - If DMAC or DTC data transfer by an RXI source is enabled, the contents of RDR can be read automatically. When the RDR data is read by the DMAC or DTC, the RDRF flag is automatically cleared to 0.
- [5] When a normal frame is received, the pin retains the high-impedance state at the timing for error signal transmission.

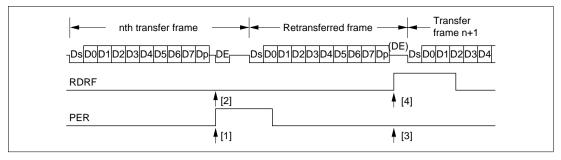


Figure 15-11 Retransfer Operation in SCI Receive Mode

- Retransfer operation when SCI is in transmit mode
 Figure 15-12 illustrates the retransfer operation when the SCI is in transmit mode.
- [6] If an error signal is sent back from the receiving end after transmission of one frame is completed, the ERS bit in SSR is set to 1. If the RIE bit in SCR is enabled at this time, an ERI interrupt request is generated. The ERS bit in SSR should be kept cleared to 0 until the next parity bit is sampled.
- [7] The TEND bit in SSR is not set for a frame for which an error signal indicating an abnormality is received.
- [8] If an error signal is not sent back from the receiving end, the ERS bit in SSR is not set.
- [9] If an error signal is not sent back from the receiving end, transmission of one frame, including a retransfer, is judged to have been completed, and the TEND bit in SSR is set to 1. If the TIE bit in SCR is enabled at this time, a TXI interrupt request is generated.
 - If data transfer by the DMAC or DTC by means of the TXI source is enabled, the next data can be written to TDR automatically. When data is written to TDR by the DMAC or DTC, the TDRE bit is automatically cleared to 0.

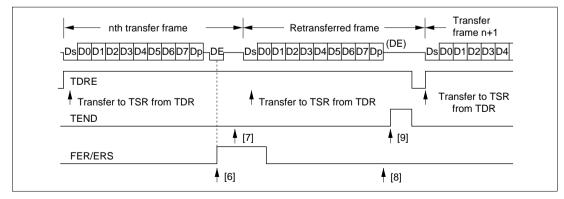


Figure 15-12 Retransfer Operation in SCI Transmit Mode

Section 16 A/D Converter

16.1 Overview

The H8S/2357 Series incorporates a successive approximation type 10-bit A/D converter that allows up to eight analog input channels to be selected.

16.1.1 Features

A/D converter features are listed below

- 10-bit resolution
- Eight input channels
- Settable analog conversion voltage range
 - Conversion of analog voltages with the reference voltage pin (V_{ref}) as the analog reference voltage
- High-speed conversion
 - Minimum conversion time: 6.7 µs per channel (at 20 MHz operation)
- Choice of single mode or scan mode
 - Single mode: Single-channel A/D conversion
 - Scan mode: Continuous A/D conversion on 1 to 4 channels
- Four data registers
 - Conversion results are held in a 16-bit data register for each channel
- Sample and hold function
- Three kinds of conversion start
 - Choice of software or timer conversion start trigger (TPU or 8-bit timer), or ADTRG pin
- A/D conversion end interrupt generation
 - A/D conversion end interrupt (ADI) request can be generated at the end of A/D conversion
- Module stop mode can be set
 - As the initial setting, A/D converter operation is halted. Register access is enabled by exiting module stop mode.

16.1.2 Block Diagram

Figure 16-1 shows a block diagram of the A/D converter.

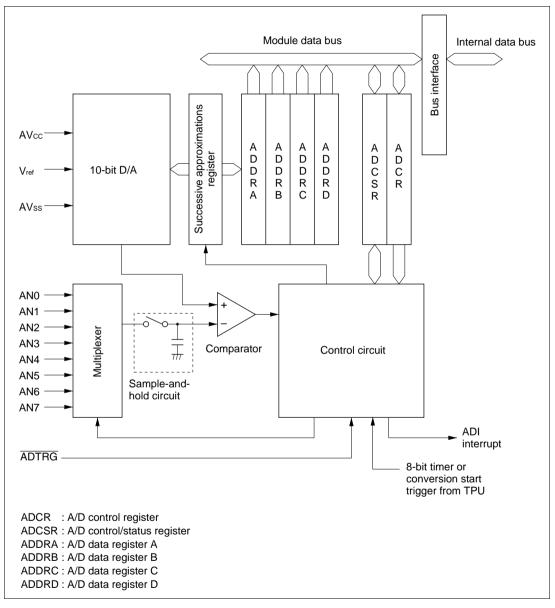


Figure 16-1 Block Diagram of A/D Converter

16.1.3 Pin Configuration

Table 16-1 summarizes the input pins used by the A/D converter.

The AV_{CC} and AV_{SS} pins are the power supply pins for the analog block in the A/D converter. The V_{ref} pin is the A/D conversion reference voltage pin.

The eight analog input pins are divided into two groups: group 0 (AN0 to AN3), and group 1 (AN4 to AN7).

Table 16-1 A/D Converter Pins

Pin Name	Symbol	I/O	Function
Analog power supply pin	AV_{CC}	Input	Analog block power supply
Analog ground pin	AV _{SS}	Input	Analog block ground and A/D conversion reference voltage
Reference voltage pin	V_{ref}	Input	A/D conversion reference voltage
Analog input pin 0	AN0	Input	Group 0 analog inputs
Analog input pin 1	AN1	Input	
Analog input pin 2	AN2	Input	<u> </u>
Analog input pin 3	AN3	Input	
Analog input pin 4	AN4	Input	Group 1 analog inputs
Analog input pin 5	AN5	Input	<u> </u>
Analog input pin 6	AN6	Input	
Analog input pin 7	AN7	Input	
A/D external trigger input pin	ADTRG	Input	External trigger input for starting A/D conversion

16.1.4 Register Configuration

Table 16-2 summarizes the registers of the A/D converter.

Table 16-2 A/D Converter Registers

Name	Abbreviation	R/W	Initial Value	Address*1
A/D data register AH	ADDRAH	R	H'00	H'FF90
A/D data register AL	ADDRAL	R	H'00	H'FF91
A/D data register BH	ADDRBH	R	H'00	H'FF92
A/D data register BL	ADDRBL	R	H'00	H'FF93
A/D data register CH	ADDRCH	R	H'00	H'FF94
A/D data register CL	ADDRCL	R	H'00	H'FF95
A/D data register DH	ADDRDH	R	H'00	H'FF96
A/D data register DL	ADDRDL	R	H'00	H'FF97
A/D control/status register	ADCSR	R/(W)*2	H'00	H'FF98
A/D control register	ADCR	R/W	H'3F	H'FF99
Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Notes: 1. Lower 16 bits of the address.

2. Bit 7 can only be written with 0 for flag clearing.

16.2 Register Descriptions

16.2.1 A/D Data Registers A to D (ADDRA to ADDRD)

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
		AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	AD1	AD0	_	_	_	_	_	_
Initial value	e :	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R/W	:	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R

There are four 16-bit read-only ADDR registers, ADDRA to ADDRD, used to store the results of A/D conversion.

The 10-bit data resulting from A/D conversion is transferred to the ADDR register for the selected channel and stored there. The upper 8 bits of the converted data are transferred to the upper byte (bits 15 to 8) of ADDR, and the lower 2 bits are transferred to the lower byte (bits 7 and 6) and stored. Bits 5 to 0 are always read as 0.

The correspondence between the analog input channels and ADDR registers is shown in table 16-3.

ADDR can always be read by the CPU. The upper byte can be read directly, but for the lower byte, data transfer is performed via a temporary register (TEMP). For details, see section 16.3, Interface to Bus Master.

The ADDR registers are initialized to H'0000 by a reset, and in standby mode or module stop mode.

Table 16-3 Analog Input Channels and Corresponding ADDR Registers

Analog Input Channel

Group 0	Group 1	A/D Data Register	
AN0	AN4	ADDRA	
AN1	AN5	ADDRB	
AN2	AN6	ADDRC	
AN3	AN7	ADDRD	

16.2.2 A/D Control/Status Register (ADCSR)

Bit	:	7	6	5	4	3	2	1	0
		ADF	ADIE	ADST	SCAN	CKS	CH2	CH1	CH0
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/(W)*	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Note: *Only 0 can be written to bit 7, to clear this flag.

ADCSR is an 8-bit readable/writable register that controls A/D conversion operations and shows the status of the operation.

ADCSR is initialized to H'00 by a reset, and in hardware standby mode or module stop mode.

Bit 7—A/D End Flag (ADF): Status flag that indicates the end of A/D conversion.

Bit 7 ADF	Description							
0	[Clearing conditions] (Initial value							
	 When 0 is written to the ADF flag after reading ADF = 1 							
	 When the DTC is activated by an ADI interrupt and ADDR is read 							
1	[Setting conditions]							
	Single mode: When A/D conversion ends							
	Scan mode: When A/D conversion ends on all specified channels							

Bit 6—A/D Interrupt Enable (ADIE): Selects enabling or disabling of interrupt (ADI) requests at the end of A/D conversion.

Bit 6		
ADIE	Description	
0	A/D conversion end interrupt (ADI) request disabled	(Initial value)
1	A/D conversion end interrupt (ADI) request enabled	

Bit 5—A/D Start (ADST): Selects starting or stopping on A/D conversion. Holds a value of 1 during A/D conversion.

The ADST bit can be set to 1 by software, a timer conversion start trigger, or the A/D external trigger input pin (\overline{ADTRG}) .

Bit 5 ADST	Description								
	•	A/D conversi	on stopped	(Initial value)					
1	•	Single mode: A/D conversion is started. Cleared to 0 automatically whe conversion on the specified channel ends							
	•	Scan mode:	A/D conversion is started. Conversion continues selected channels until ADST is cleared to 0 by sa transition to standby mode or module stop mode.	software, a reset, or					

Bit 4—Scan Mode (SCAN): Selects single mode or scan mode as the A/D conversion operating mode. See section 16.4, Operation, for single mode and scan mode operation. Only set the SCAN bit while conversion is stopped (ADST = 0).

Bit 4	
SCAN	Description

	2 000 i piioi	
0	Single mode	(Initial value)
1	Scan mode	

Bit 3—Clock Select (CKS): Sets the A/D conversion time. Only change the conversion time while conversion is stopped (ADST = 0).

Bit 3		
CKS	Description	
0	Conversion time = 266 states (max.)	(Initial value)
1	Conversion time = 134 states (max.)	

Bits 2 to 0—Channel Select 2 to 0 (CH2 to CH0): Together with the SCAN bit, these bits select the analog input channels.

Only set the input channel while conversion is stopped (ADST = 0).

Group Selection	Chan	nel Selection	Description				
CH2	CH1	CH0	Single Mode	Scan Mode			
0	0	0	AN0 (Initial value)	AN0			
		1	AN1	AN0, AN1			
	1	0	AN2	AN0 to AN2			
		1	AN3	AN0 to AN3			
1	0	0	AN4	AN4			
		1	AN5	AN4, AN5			
	1	0	AN6	AN4 to AN6			
		1	AN7	AN4 to AN7			

16.2.3 A/D Control Register (ADCR)

Bit	:	7	6	5	4	3	2	1	0
		TRGS1	TRGS0	_	_	_	_	_	_
Initial va	alue :	0	0	1	1	1	1	1	1
R/W	:	R/W	R/W	_	_	—/(R/W)*	—/(R/W)*	_	_

Note: * Applies to the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390

ADCR is an 8-bit readable/writable register that enables or disables external triggering of A/D conversion operations.

ADCR is initialized to H'3F by a reset, and in standby mode or module stop mode.

Bits 7 and 6—Timer Trigger Select 1 and 0 (TRGS1, TRGS0): Select enabling or disabling of the start of A/D conversion by a trigger signal. Only set bits TRGS1 and TRGS0 while conversion is stopped (ADST = 0).

Bit 7 TRGS1	Bit 6 TRGS0	Description
0	0	A/D conversion start by external trigger is disabled (Initial value)
	1	A/D conversion start by external trigger (TPU) is enabled
1	0	A/D conversion start by external trigger (8-bit timer) is enabled
	1	A/D conversion start by external trigger pin (ADTRG) is enabled

(1) For H8S/2357 and H8S/2352

Bits 5 to 0—Reserved: They are always read as 1 and cannot be modified.

(2) For H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390

Bits 5, 4, 1, and 0—Reserved: They are always read as 1 and cannot be modified.

Bits 3 and 2—Reserved: Should always be written with 1.

16.2.4 Module Stop Control Register (MSTPCR)

			MSTPCRH				MSTPCRL										
Bit		15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial value	:	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	1
R/W	: R	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP9 bit in MSTPCR is set to 1, A/D converter operation stops at the end of the bus cycle and a transition is made to module stop mode. Registers cannot be read or written to in module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 9—Module Stop (MSTP9): Specifies the A/D converter module stop mode.

Bit 9 MSTP9	Description	
0	A/D converter module stop mode cleared	
1	A/D converter module stop mode set	(Initial value)

16.3 Interface to Bus Master

ADDRA to ADDRD are 16-bit registers, and the data bus to the bus master is 8 bits wide. Therefore, in accesses by the bus master, the upper byte is accessed directly, but the lower byte is accessed via a temporary register (TEMP).

A data read from ADDR is performed as follows. When the upper byte is read, the upper byte value is transferred to the CPU and the lower byte value is transferred to TEMP. Next, when the lower byte is read, the TEMP contents are transferred to the CPU.

When reading ADDR. always read the upper byte before the lower byte. It is possible to read only the upper byte, but if only the lower byte is read, incorrect data may be obtained.

Figure 16-2 shows the data flow for ADDR access.

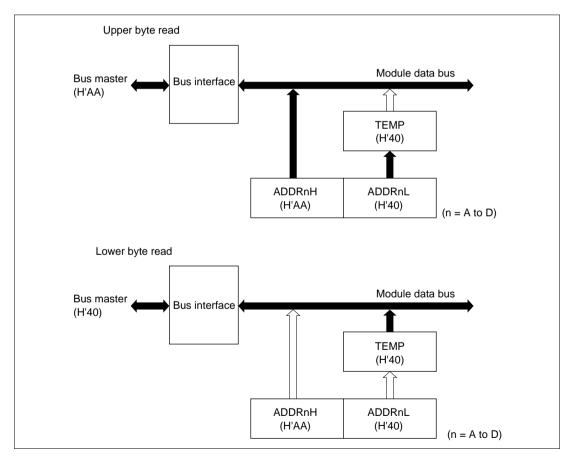


Figure 16-2 ADDR Access Operation (Reading H'AA40)

16.4 Operation

The A/D converter operates by successive approximation with 10-bit resolution. It has two operating modes: single mode and scan mode.

16.4.1 Single Mode (SCAN = 0)

Single mode is selected when A/D conversion is to be performed on a single channel only. A/D conversion is started when the ADST bit is set to 1, according to the software or external trigger input. The ADST bit remains set to 1 during A/D conversion, and is automatically cleared to 0 when conversion ends.

On completion of conversion, the ADF flag is set to 1. If the ADIE bit is set to 1 at this time, an ADI interrupt request is generated. The ADF flag is cleared by writing 0 after reading ADCSR.

When the operating mode or analog input channel must be changed during analog conversion, to prevent incorrect operation, first clear the ADST bit to 0 in ADCSR to halt A/D conversion. After making the necessary changes, set the ADST bit to 1 to start A/D conversion again. The ADST bit can be set at the same time as the operating mode or input channel is changed.

Typical operations when channel 1 (AN1) is selected in single mode are described next. Figure 16-3 shows a timing diagram for this example.

- [1] Single mode is selected (SCAN = 0), input channel AN1 is selected (CH2 = 0, CH1 = 0, CH0 = 1), the A/D interrupt is enabled (ADIE = 1), and A/D conversion is started (ADST = 1).
- [2] When A/D conversion is completed, the result is transferred to ADDRB. At the same time the ADF flag is set to 1, the ADST bit is cleared to 0, and the A/D converter becomes idle.
- [3] Since ADF = 1 and ADIE = 1, an ADI interrupt is requested.
- [4] The A/D interrupt handling routine starts.
- [5] The routine reads ADCSR, then writes 0 to the ADF flag.
- [6] The routine reads and processes the connection result (ADDRB).
- [7] Execution of the A/D interrupt handling routine ends. After that, if the ADST bit is set to 1, A/D conversion starts again and steps [2] to [7] are repeated.

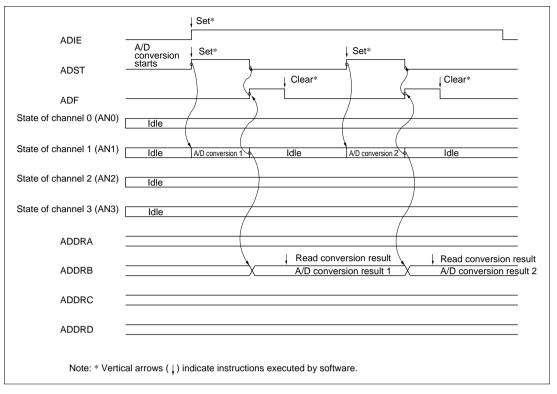


Figure 16-3 Example of A/D Converter Operation (Single Mode, Channel 1 Selected)

16.4.2 Scan Mode (SCAN = 1)

Scan mode is useful for monitoring analog inputs in a group of one or more channels. When the ADST bit is set to 1 by a software, timer or external trigger input, A/D conversion starts on the first channel in the group (AN0). When two or more channels are selected, after conversion of the first channel ends, conversion of the second channel (AN1) starts immediately. A/D conversion continues cyclically on the selected channels until the ADST bit is cleared to 0. The conversion results are transferred for storage into the ADDR registers corresponding to the channels.

When the operating mode or analog input channel must be changed during analog conversion, to prevent incorrect operation, first clear the ADST bit to 0 in ADCSR to halt A/D conversion. After making the necessary changes, set the ADST bit to 1 to start A/D conversion again. The ADST bit can be set at the same time as the operating mode or input channel is changed.

Typical operations when three channels (AN0 to AN2) are selected in scan mode are described next. Figure 16-4 shows a timing diagram for this example.

- [1] Scan mode is selected (SCAN = 1), scan group 0 is selected (CH2 = 0), analog input channels AN0 to AN2 are selected (CH1 = 1, CH0 = 0), and A/D conversion is started (ADST = 1)
- [2] When A/D conversion of the first channel (AN0) is completed, the result is transferred to ADDRA. Next, conversion of the second channel (AN1) starts automatically.
- [3] Conversion proceeds in the same way through the third channel (AN2).
- [4] When conversion of all the selected channels (AN0 to AN2) is completed, the ADF flag is set to 1 and conversion of the first channel (AN0) starts again. If the ADIE bit is set to 1 at this time, an ADI interrupt is requested after A/D conversion ends.
- [5] Steps [2] to [4] are repeated as long as the ADST bit remains set to 1. When the ADST bit is cleared to 0, A/D conversion stops. After that, if the ADST bit is set to 1, A/D conversion starts again from the first channel (AN0).

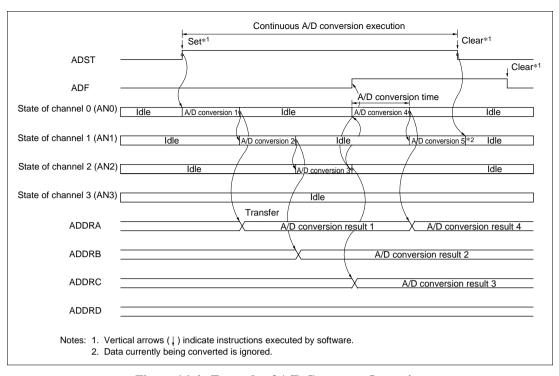


Figure 16-4 Example of A/D Converter Operation (Scan Mode, Channels AN0 to AN2 Selected)

16.4.3 Input Sampling and A/D Conversion Time

The A/D converter has a built-in sample-and-hold circuit. The A/D converter samples the analog input at a time t_D after the ADST bit is set to 1, then starts conversion. Figure 16-5 shows the A/D conversion timing. Table 16-4 indicates the A/D conversion time.

As indicated in figure 16-5, the A/D conversion time includes t_D and the input sampling time. The length of t_D varies depending on the timing of the write access to ADCSR. The total conversion time therefore varies within the ranges indicated in table 16-4.

In scan mode, the values given in table 16-4 apply to the first conversion time. In the second and subsequent conversions the conversion time is fixed at 256 states when CKS = 0 or 128 states when CKS = 1.

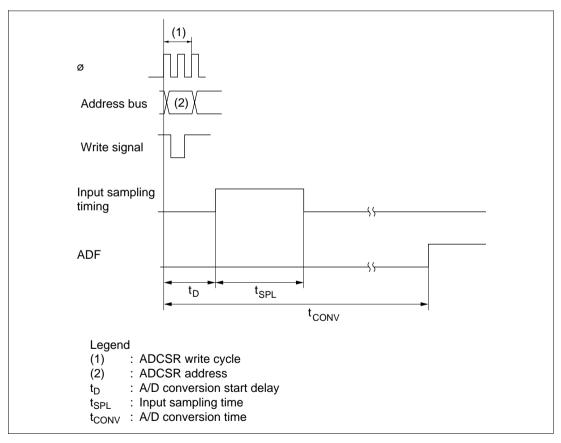


Figure 16-5 A/D Conversion Timing

Table 16-4 A/D Conversion Time (Single Mode)

			CKS =	= 0	CKS = 1		
Item	Symbol	Min	Тур	Max	Min	Тур	Max
A/D conversion start delay	t _D	10	_	17	6	_	9
Input sampling time	t _{SPL}	_	63	_	_	31	_
A/D conversion time	t _{conv}	259	_	266	131	_	134

Note: Values in the table are the number of states.

16.4.4 External Trigger Input Timing

A/D conversion can be externally triggered. When the TRGS1 and TRGS0 bits are set to 11 in ADCR, external trigger input is enabled at the ADTRG pin. A falling edge at the ADTRG pin sets the ADST bit to 1 in ADCSR, starting A/D conversion. Other operations, in both single and scan modes, are the same as if the ADST bit has been set to 1 by software. Figure 16-6 shows the timing.

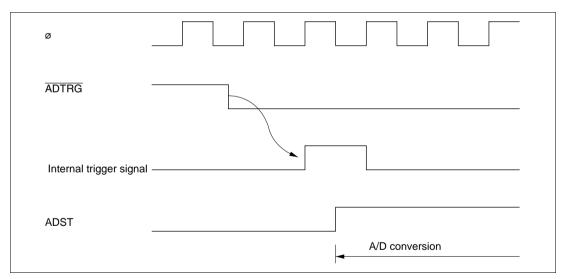


Figure 16-6 External Trigger Input Timing

16.5 Interrupts

The A/D converter generates an A/D conversion end interrupt (ADI) at the end of A/D conversion. ADI interrupt requests can be enabled or disabled by means of the ADIE bit in ADCSR.

The DTC or DMAC can be activated by an ADI interrupt. Having the converted data read by the DTC or DMAC in response to an ADI interrupt enables continuous conversion to be achieved without imposing a load on software.

The A/D converter interrupt source is shown in table 16-5.

Table 16-5 A/D Converter Interrupt Source

Interrupt Source	Description	DTC or DMAC Activation
ADI	Interrupt due to end of conversion	Possible

16.6 Usage Notes

The following points should be noted when using the A/D converter.

Setting Range of Analog Power Supply and Other Pins:

- (1) Analog input voltage range
 - The voltage applied to analog input pins AN0 to AN7 during A/D conversion should be in the range AV_{SS} ANn V_{ref} .
- (2) Relation between $AV_{\text{CC}},\,AV_{\text{SS}}$ and $V_{\text{CC}},\,V_{\text{SS}}$

As the relationship between AV_{CC} , AV_{SS} and V_{CC} , V_{SS} , set $AV_{SS} = V_{SS}$. If the A/D converter is not used, the AV_{CC} and AV_{SS} pins must on no account be left open.

(3) V_{ref} input range

The analog reference voltage input at the V_{ref} pin set in the range V_{ref} AV $_{\text{CC}}$.

If conditions (1), (2), and (3) above are not met, the reliability of the device may be adversely affected.

Notes on Board Design: In board design, digital circuitry and analog circuitry should be as mutually isolated as possible, and layout in which digital circuit signal lines and analog circuit signal lines cross or are in close proximity should be avoided as far as possible. Failure to do so may result in incorrect operation of the analog circuitry due to inductance, adversely affecting A/D conversion values.

Also, digital circuitry must be isolated from the analog input signals (AN0 to AN7), analog reference power supply ($V_{\rm ref}$), and analog power supply ($AV_{\rm CC}$) by the analog ground ($AV_{\rm SS}$). Also, the analog ground ($AV_{\rm SS}$) should be connected at one point to a stable digital ground ($V_{\rm SS}$) on the board.

Notes on Noise Countermeasures: A protection circuit connected to prevent damage due to an abnormal voltage such as an excessive surge at the analog input pins (AN0 to AN7) and analog reference power supply (V_{ref}) should be connected between AV_{CC} and AV_{SS} as shown in figure 16-7.

Also, the bypass capacitors connected to AV_{CC} and V_{ref} and the filter capacitor connected to AN0 to AN7 must be connected to AV_{SS} .

If a filter capacitor is connected as shown in figure 16-7, the input currents at the analog input pins (AN0 to AN7) are averaged, and so an error may arise. Also, when A/D conversion is performed frequently, as in scan mode, if the current charged and discharged by the capacitance of the sample-and-hold circuit in the A/D converter exceeds the current input via the input impedance (R_{in}), an error will arise in the analog input pin voltage. Careful consideration is therefore required when deciding the circuit constants.

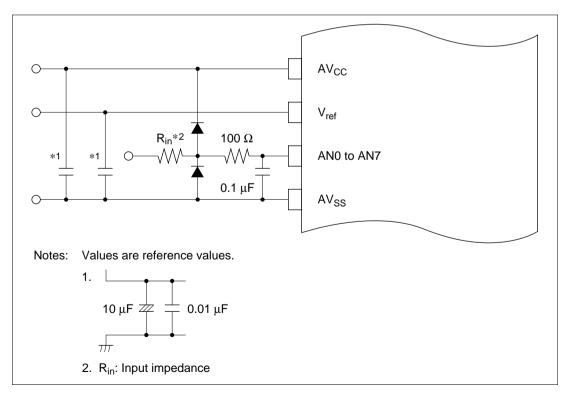


Figure 16-7 Example of Analog Input Protection Circuit

A/D Conversion Precision Definitions: H8S/2357 Series A/D conversion precision definitions are given below.

Resolution

The number of A/D converter digital output codes

Offset error

The deviation of the analog input voltage value from the ideal A/D conversion characteristic when the digital output changes from the minimum voltage value B'0000000000 (H'000) to B'0000000001 (H'001) (see figure 16-9).

Full-scale error

The deviation of the analog input voltage value from the ideal A/D conversion characteristic when the digital output changes from B'1111111110 (H'3FE) to B'1111111111 (H'3FF) (see figure 16-9).

Quantization error

The deviation inherent in the A/D converter, given by 1/2 LSB (see figure 16-8).

• Nonlinearity error

The error with respect to the ideal A/D conversion characteristic between the zero voltage and the full-scale voltage. Does not include the offset error, full-scale error, or quantization error.

Absolute precision

The deviation between the digital value and the analog input value. Includes the offset error, full-scale error, quantization error, and nonlinearity error.

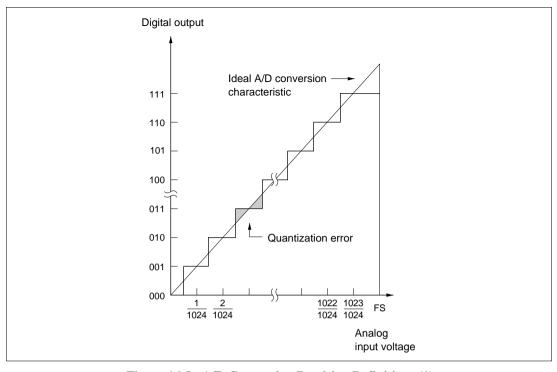


Figure 16-8 A/D Conversion Precision Definitions (1)

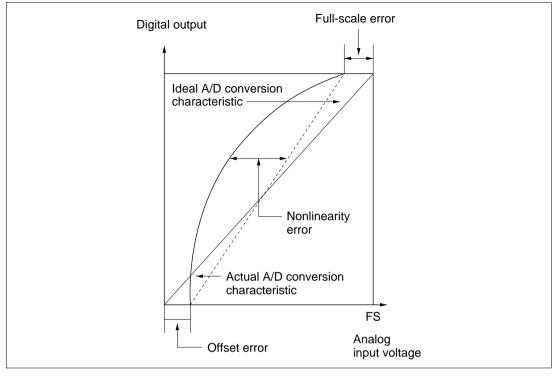


Figure 16-9 A/D Conversion Precision Definitions (2)

Permissible Signal Source Impedance: H8S/2357 Series analog input is designed so that conversion precision is guaranteed for an input signal for which the signal source impedance is $10 \, \mathrm{k}$ or less. This specification is provided to enable the A/D converter's sample-and-hold circuit input capacitance to be charged within the sampling time; if the sensor output impedance exceeds $10 \, \mathrm{k}$, charging may be insufficient and it may not be possible to guarantee the A/D conversion precision.

However, if a large capacitance is provided externally, the input load will essentially comprise only the internal input resistance of 10 k, and the signal source impedance is ignored.

However, since a low-pass filter effect is obtained in this case, it may not be possible to follow an analog signal with a large differential coefficient (e.g., 5 mV/µs or greater).

When converting a high-speed analog signal, a low-impedance buffer should be inserted.

Influences on Absolute Precision: Adding capacitance results in coupling with GND, and therefore noise in GND may adversely affect absolute precision. Be sure to make the connection to an electrically stable GND such as AV_{SS} .

Care is also required to insure that filter circuits do not communicate with digital signals on the mounting board, so acting as antennas.

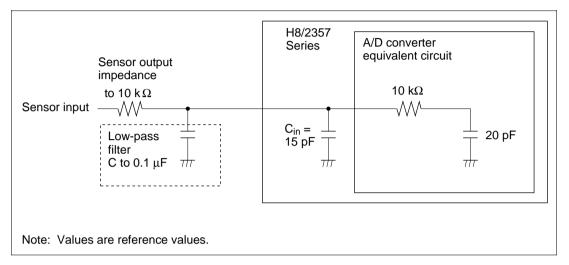


Figure 16-10 Example of Analog Input Circuit

Section 17 D/A Converter

17.1 Overview

The H8S/2357 Series includes a two-channel D/A converter.

17.1.1 Features

D/A converter features are listed below

- 8-bit resolution
- Two output channels
- Maximum conversion time of 10 µs (with 20 pF load)
- Output voltage of 0 V to V_{ref}
- D/A output hold function in software standby mode
- Module stop mode can be set
 - As the initial setting, D/A converter operation is halted. Register access is enabled by exiting module stop mode.

17.1.2 Block Diagram

Figure 17-1 shows a block diagram of the D/A converter.

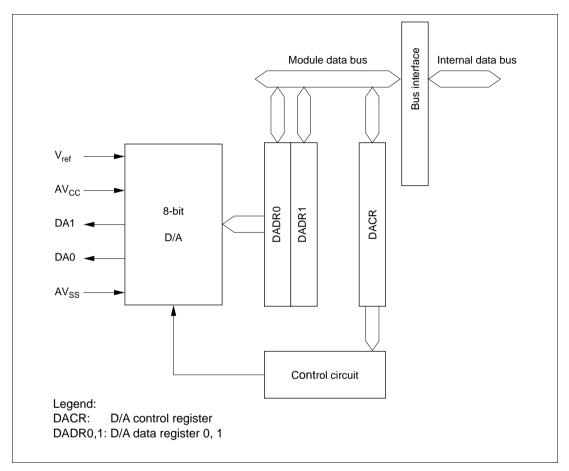


Figure 17-1 Block Diagram of D/A Converter

17.1.3 Pin Configuration

Table 17-1 summarizes the input and output pins of the D/A converter.

Table 17-1 Pin Configuration

Pin Name	Symbol	I/O	Function
Analog power pin	AV_CC	Input	Analog power source
Analog ground pin	AV _{SS}	Input	Analog ground and reference voltage
Analog output pin 0	DA0	Output	Channel 0 analog output
Analog output pin 1	DA1	Output	Channel 1 analog output
Reference voltage pin	V_{ref}	Input	Analog reference voltage

17.1.4 Register Configuration

Table 17-2 summarizes the registers of the D/A converter.

Table 17-2 D/A Converter Registers

Name	Abbreviation	R/W	Initial Value	Address*
D/A data register 0	DADR0	R/W	H'00	H'FFA4
D/A data register 1	DADR1	R/W	H'00	H'FFA5
D/A control register	DACR	R/W	H'1F	H'FFA6
Module stop control register	MSTPCR	R/W	H'3FFF	H'FF3C

Note:* Lower 16 bits of the address.

17.2 Register Descriptions

17.2.1 D/A Data Registers 0 and 1 (DADR0, DADR1)

Bit	:	7	6	5	4	3	2	1	0
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DADR0 and DADR1 are 8-bit readable/writable registers that store data for conversion.

Whenever output is enabled, the values in DADR0 and DADR1 are converted and output from the analog output pins.

DADR0 and DADR1 are each initialized to H'00 by a reset and in hardware standby mode.

17.2.2 D/A Control Register (DACR)

Bit	:	7	6	5	4	3	2	1	0
		DAOE1	DAOE0	DAE	_	_	_	_	_
Initial va	alue :	0	0	0	1	1	1	1	1
R/W	:	R/W	R/W	R/W	_	_	_	_	_

DACR is an 8-bit readable/writable register that controls the operation of the D/A converter.

DACR is initialized to H'1F by a reset and in hardware standby mode.

Bit 7—D/A Output Enable 1 (DAOE1): Controls D/A conversion and analog output for channel 1.

Bit 7

DAOE1	Description	
0	Analog output DA1 is disabled	(Initial value)
1	Channel 1 D/A conversion is enabled; analog output DA1 is enabled	

Bit 6—D/A Output Enable 0 (DAOE0): Controls D/A conversion and analog output for channel 0.

Bit 6 DAOE0	Description	
0	Analog output DA0 is disabled	(Initial value)
1	Channel 0 D/A conversion is enabled; analog output DA0 is enabled	

Bit 5—D/A Enable (DAE): The DAOE0 and DAOE1 bits both control D/A conversion. When the DAE bit is cleared to 0, the channel 0 and 1 D/A conversions are controlled independently. When the DAE bit is set to 1, the channel 0 and 1 D/A conversions are controlled together.

Output of resultant conversions is always controlled independently by the DAOE0 and DAOE1 bits.

Bit 7 DAOE1	Bit 6 DAOE0	Bit 5 DAE	Description
0	0	*	Channel 0 and 1 D/A conversions disabled
	1	0	Channel 0 D/A conversion enabled Channel 1 D/A conversion disabled
		1	Channel 0 and 1 D/A conversions enabled
1	0	0	Channel 0 D/A conversion disabled Channel 1 D/A conversion enabled
		1	Channel 0 and 1 D/A conversions enabled
	1	*	Channel 0 and 1 D/A conversions enabled

*: Don't care

If the H8S/2357 Series enters software standby mode when D/A conversion is enabled, the D/A output is held and the analog power current is the same as during D/A conversion. When it is necessary to reduce the analog power current in software standby mode, clear both the DAOE0 and DAOE1 bits to 0 to disable D/A output.

Bits 4 to 0—Reserved: These bits cannot be modified and are always read as 1.

17.2.3 Module Stop Control Register (MSTPCR)

			MSTPCRH						MSTPCRL								
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial value	:	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	1
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

When the MSTP10 bit in MSTPCR is set to 1, D/A converter operation stops at the end of the bus cycle and a transition is made to module stop mode. Registers cannot be read or written to in module stop mode. For details, see section 21.5, Module Stop Mode.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 10—Module Stop (MSTP10): Specifies the D/A converter module stop mode.

Bit 10		
MSTP10	Description	
0	D/A converter module stop mode cleared	
1	D/A converter module stop mode set	(Initial value)

17.3 Operation

The D/A converter includes D/A conversion circuits for two channels, each of which can operate independently.

D/A conversion is performed continuously while enabled by DACR. If either DADR0 or DADR1 is written to, the new data is immediately converted. The conversion result is output by setting the corresponding DAOE0 or DAOE1 bit to 1.

The operation example described in this section concerns D/A conversion on channel 0. Figure 17-2 shows the timing of this operation.

- [1] Write the conversion data to DADR0.
- [2] Set the DAOE0 bit in DACR to 1. D/A conversion is started and the DA0 pin becomes an output pin. The conversion result is output after the conversion time has elapsed. The output value is expressed by the following formula:

$$\frac{\text{DADR contents}}{256} \times V_{\text{ref}}$$

The conversion results are output continuously until DADR0 is written to again or the DAOE0 bit is cleared to 0.

- [3] If DADR0 is written to again, the new data is immediately converted. The new conversion result is output after the conversion time has elapsed.
- [4] If the DAOE0 bit is cleared to 0, the DA0 pin becomes an input pin.

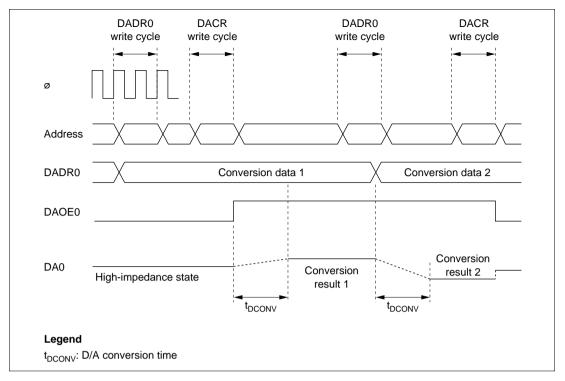


Figure 17-2 Example of D/A Converter Operation

Section 18 RAM

18.1 Overview

The H8S/2357, H8S/2352, H8S/2398, H8S/2396, H8S/2395 and H8S/2392 have 8 kbytes of on-chip high-speed static RAM. The H8S/2394 has 32 kbytes of on-chip high-speed static RAM. The H8S/2390 has 4 kbytes of on-chip high-speed static RAM.

The on-chip RAM can be enabled or disabled by means of the RAM enable bit (RAME) in the system control register (SYSCR).

18.1.1 Block Diagram

Figure 18-1 shows a block diagram of the 8-kbytes of on-chip RAM.

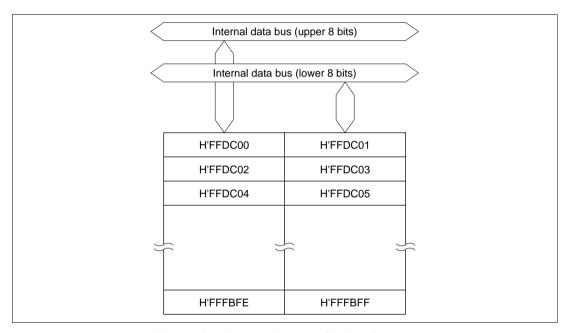


Figure 18-1 Block Diagram of RAM (8 kbyte)

18.1.2 Register Configuration

The on-chip RAM is controlled by SYSCR. Table 18-1 shows the address and initial value of SYSCR.

Table 18-1 RAM Register

Name	Abbreviation	R/W	Initial Value	Address*
System control register	SYSCR	R/W	H'01	H'FF39

Note: * Lower 16 bits of the address.

18.2 Register Descriptions

18.2.1 System Control Register (SYSCR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	INTM1	INTM0	NMIEG	_	_	RAME
Initial va	lue :	0	0	0	0	0	0	0	1
R/W	:	R/W	_	R/W	R/W	R/W	_	R/W	R/W

The on-chip RAM is enabled or disabled by the RAME bit in SYSCR. For details of other bits in SYSCR, see section 3.2.2, System Control Register (SYSCR).

Bit 0—RAM Enable (RAME): Enables or disables the on-chip RAM. The RAME bit is initialized when the reset state is released. It is not initialized in software standby mode.

Bit 0		
RAME	Description	
0	On-chip RAM is disabled	
1	On-chip RAM is enabled	(Initial value)

18.3 Operation

When the RAME bit is set to 1, accesses to addresses H'FFDC00 to H'FFFBFF* are directed to the on-chip RAM. When the RAME bit is cleared to 0, the off-chip address space is accessed.

Since the on-chip RAM is connected to the CPU by an internal 16-bit data bus, it can be written to and read in byte or word units. Each type of access can be performed in one state.

Even addresses use the upper 8 bits, and odd addresses use the lower 8 bits. Word data must start at an even address.

Note: * Since the on-chip RAM capacitance differs according to each product, see section 3.5, Memory Map in Each Operating Mode.

18.4 Usage Note

DTC register information can be located in addresses H'FFF800 to H'FFFBFF. When the DTC is used, the RAME bit must not be cleared to 0.

Section 19 ROM

19.1 Overview

This series has 512, 384, 256, or 128 kbytes of flash memory, 256 or 128 kbytes of mask ROM, or 128 kbytes of PROM. The ROM is connected to the H8S/2000 CPU by a 16-bit data bus. The CPU accesses both byte data and word data in one state, making possible rapid instruction fetches and high-speed processing.

The on-chip ROM is enabled or disabled by setting the mode pins (MD₂, MD₁, and MD₀) and bit EAE in BCRL.

The flash memory versions of this LSI can be erased and programmed on-board as well as with a PROM programmer.

The PROM version of the H8S/2357 can be programmed with a PROM programmer, by setting PROM mode.

19.1.1 Block Diagram

Figure 19-1 shows a block diagram of the on-chip ROM.

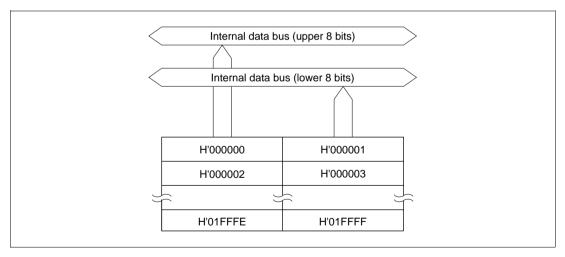


Figure 19-1 Block Diagram of ROM (128 Kbytes)

19.1.2 Register Configuration

The H8S/2357's on-chip ROM is controlled by the mode pins and register BCRL. The register configuration is shown in table 19-1.

Table 19-1 ROM Register

Name	Abbreviation	R/W	Initial Value	Address*
Mode control register	MDCR	R/W	Undefined	H'FF3B
Bus control register L	BCRL	R/W	Undefined	H'FED5

Note: * Lower 16 bits of the address.

19.2 Register Descriptions

19.2.1 Mode Control Register (MDCR)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	_	MDS2	MDS1	MDS0
Initial va	alue :	1	0	0	0	0	*	*	*
R/W	:	_	_	_	_	_	R	R	R

Note: * Determined by pins MD₂ to MD₀.

MDCR is an 8-bit read-only register that indicates the current operating mode of the H8S/2357 Series.

Bit 7—Reserved: This bit cannot be modified and is always read as 1.

Bits 6 to 3—Reserved: These bits cannot be modified and are always read as 0.

Bits 2 to 0—Mode Select 2 to 0 (MDS2 to MDS0): These bits indicate the input levels at pins MD_2 to MD_0 (the current operating mode). Bits MDS_2 to MDS_0 correspond to pins MD_2 to MDS_0 are read-only bits, and cannot be written to. The mode pin $(MD_2$ to MD_0) input levels are latched into these bits when MDCR is read. These latches are canceled by a power-on reset, but are retained after a manual reset*.

Note: * Manual reset is only supported in the H8S/2357 ZTAT version.

19.2.2 Bus Control Register L (BCRL)

Bit	:	7	6	5	4	3	2	1	0
		BRLE	BREQOE	EAE	LCASS	DDS		WDBE	WAITE
Initial va	alue :	0	0	1	1	1	1	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Enabling or disabling of part of the H8S/2357's on-chip ROM area can be selected by means of the EAE bit in BCRL. For details of the other bits in BCRL, see 6.2.5, Bus Control Register L.

Bit 5—External Address Enable (EAE): Selects whether addresses H'010000 to H'01FFFF*² are to be internal addresses or external addresses.

_	-/-	_	_	_	_		ا ی	_	'			_					
F	AE	D	١.	_	١.	2	۰,	ri	ir	٠.	i,	•	n				
E	Sit 5																

0	Addresses H'010000 to H'01FFFF*2 are in on-chip ROM					
1	Addresses H'010000 to H'01FFFF*2 are external addresses (external exmode)	rpansion				
	or a reserved area*1 (single-chip mode).	(Initial value)				

Notes: 1. Reserved areas should not be accessed.

 Addresses H'010000 to H'01FFFF are in the H8S/2357. Addresses H'010000 to H'03FFFF are in the H8S/2398. Addresses H'010000 to H'05FFFF are in the H8S/2395. Addresses H'010000 to H'07FFFF are in the H8S/2396.

19.3 Operation

The on-chip ROM is connected to the CPU by a 16-bit data bus, and both byte and word data can be accessed in one state. Even addresses are connected to the upper 8 bits, and odd addresses to the lower 8 bits. Word data must start at an even address.

The on-chip ROM is enabled and disabled by setting the mode pins (MD₂, MD₁, and MD₀) and bit EAE in BCRL. These settings are shown in table 19-2.

Table 19-2 Operating Modes and ROM Area (H8S/2357F-ZTAT)

			Mod	de Pin		BCRL	<u>_</u>		
Operating	g Mode	FWE	MD ₂	MD₁	MD₀	EAE	On-Chip ROM		
Mode 0	_	0	0	0	0	_	_		
Mode 1					1				
Mode 2	_			1	0				
Mode 3		_			1				
Mode 4	Advanced expanded mode with on-chip ROM disabled		1	0	0	_	Disabled		
Mode 5	Advanced expanded mode with on-chip ROM disabled	_			1				
Mode 6	Advanced expanded mode	=		1	0	0	Enabled (128 kbytes)*1		
	with on-chip ROM enabled					1	Enabled (64 kbytes)		
Mode 7	Advanced single-chip mode	=			1	0	Enabled (128 kbytes)*1		
						1	Enabled (64 kbytes)		
Mode 8	_	1	0	0	0	_	_		
Mode 9		_			1				
Mode 10	Boot mode (advanced			1	0	0	Enabled (128 kbytes)*2		
	expanded mode with on- chip ROM enabled)*3					1	Enabled (64 kbytes)		
Mode 11	Boot mode (advanced	=			1	0	Enabled (128 kbytes)*2		
	single-chip mode)*4					1	Enabled (64 kbytes)		
Mode 12	_	=	1	0	0	_	_		
Mode 13	_				1				
Mode 14	User program mode (advanced expanded mode	_		1	0	0	Enabled (128 kbytes)*1		
	with on-chip ROM enabled)*3					1	Enabled (64 kbytes)		
Mode 15	User program mode	_			1	0	Enabled (128 kbytes)*1		
	(advanced single-chip mode)*4					1	Enabled (64 kbytes)		

Notes: 1. Note that in modes 6, 7, 14, and 15, the on-chip ROM that can be used after a power-on reset is the 64-kbyte area from H'000000 to H'00FFFF.

- 2. Note that in the mode 10 and mode 11 boot modes, the on-chip ROM that can be used immediately after all flash memory is erased by the boot program is the 64-kbyte area from H'000000 to H'00FFFF.
- 3. Apart from the fact that flash memory can be erased and programmed, operation is the same as in advanced expanded mode with on-chip ROM enabled.

4. Apart from the fact that flash memory can be erased and programmed, operation is the same as in advanced single-chip mode.

Table 19-3 Operating Modes and ROM Area (ZTAT or Mask ROM, ROMless, Versions H8S/2395F-ZTAT, H8S/2396F-ZTAT, H8S/2398F-ZTAT)

				Pin	BCRL	-
Operating Mode		MD2	MD1	MD0	EAE	On-Chip ROM
Mode 0	_	0	0	0	_	_
Mode 1	_			1	_	
Mode 2*2	-		1	0	=	
Mode 3*2	-			1	=	
Mode 4*3	Advanced expanded mode with on-chip ROM disabled	1	0	0	_	Disabled
Mode 5*3	Advanced expanded mode with on-chip ROM disabled	_		1	_	
Mode 6	Advanced expanded mode		1	0	0	Enabled (128 kbytes)*1
	with on-chip ROM enabled				1	Enabled (64 kbytes)
Mode 7	Advanced single-chip mode			1	0	Enabled (128 kbytes)*1
					1	Enabled (64 kbytes)

Note: 1. Modes 6 and 7, the on-chip ROM available after a power-on reset is the 64-kbyte area comprising addresses H'000000 to H'00FFFF.
 Since the on-chip ROM area differs according to each product, see section 3.5, Memory Map in Each Operating Mode.

- 2. In the H8S/2395 F-ZTAT, H8S/2396 F-ZTAT, and H8S/2398 F-ZTAT versions, modes 2 and 3 indicate boot mode. For details on boot mode of the H8S/2395 F-ZTAT and H8S/2396 F-ZTAT versions, refer to table 19-56 in section 19.26, On-Board Programming Modes. For details on boot mode of the H8S/2398 F-ZTAT version, refer to table 19-35 in section 19.17, On-Board Programming Modes. In addition, for details on user program mode of said products, refer also to tables 19-56 and 19-35 in sections 19.26 and 19.17, On-Board Programming Modes.
- 3. In ROMless version, only modes 4 and 5 are available.

19.4 PROM Mode (H8S/2357ZTAT)

19.4.1 PROM Mode Setting

The PROM version of the H8S/2357 suspends its microcontroller functions when placed in PROM mode, enabling the on-chip PROM to be programmed. This programming can be done with a PROM programmer set up in the same way as for the HN27C101 EPROM ($V_{PP} = 12.5 \text{ V}$). Use of a 120-pin/32-pin socket adapter enables programming with a commercial PROM programmer.

Note that the PROM programmer should not be set to page mode as the H8S/2357 does not support page programming.

Table 19-4 shows how PROM mode is selected.

Table 19-4 Selecting PROM Mode

Pin Names	Setting
MD ₂ , MD ₁ , MD ₀	Low
STBY	_
PA ₂ , PA ₁	High

19.4.2 Socket Adapter and Memory Map

Programs can be written and verified by attaching a socket adapter to the PROM programmer to convert from a 120/128-pin arrangement to a 32-pin arrangement. Table 19-5 gives ordering information for the socket adapter, and figure 19-2 shows the wiring of the socket adapter. Figure 19-3 shows the memory map in PROM mode.

					HN27C101
TFP-120	FP-128	Pin		Pin	(32 Pins)
73	81	RES		V _{PP}	1
43	49	PD ₀		EO ₀	13
44	50	PD ₁		EO ₁	14
45	51	PD ₂		EO ₂	15
46	52	PD ₃		EO ₃	17
48	54	PD ₄		EO ₄	18
49	55	PD ₅		EO ₅	19
50	56	PD ₆		EO ₆	20
51	57	PD ₇		EO ₇	21
2	6	PC ₀		EA ₀	12
3	7	PC ₁		EA ₁	11
4	8	PC ₂		EA ₂	10
5	9	PC ₃		EA ₃	9
7	11	PC ₄		EA ₄	8
8	12	PC ₅		EA ₅	7
9	13	PC ₆		EA ₆	6
10	14	PC ₇		EA ₇	5
11	15	PB ₀		EA ₈	27
74	82	NMI		EA ₉	26
13	17	PB ₂		EA ₁₀	23
14	18	PB ₃		EA ₁₁	25
16	20	PB ₄		EA ₁₂	4
17	21	PB ₅		EA ₁₃	28
18	22	PB ₆		EA ₁₄	29
19	23	PB ₇		EA ₁₅	3
20	24	PA ₀		EA ₁₆	2
86	94	PF ₂		CE	22
12	16	PB ₁		ŌĒ	24
87	95	PF ₁		PGM	31
, 33, 52, 76, 81	5, 39, 58, 84, 89	v_{cc}	1	V _{CC}	32
93	103	AV _{CC}	 		
94	104	V _{ref}	 		
21	25	PA ₁	 		
22	26	PA ₂			
6, 15, 24, 38,	3, 10, 19, 28, 35,	V _{SS}		V _{SS}	16
47, 59, 79, 104	36, 44, 53, 65, 67,				
	68, 87, 99, 100, 114				
103	113	AV _{SS}	 		
75	83	STBY	 	V _{PP} : Progr	ramming power
113	123	MD_0	 	suppl	ly (12.5 V)
114	124	MD ₁	 	EO ₇ to EO ₀ : Data	input/output
115	125	MD_2		EA ₁₆ to EA ₀ : Addre	ess input ut enable
· Pins not show	n in this figure shoul	d be left o			enable

Figure 19-2 Wiring of 120/128-Pin Socket Adapter

Table 19-5 Socket Adapter

Microcontroller	Package	Socket Adapter		
H8S/2357	120 pin TQFP (TFP-120)	HS2655ESNS1H		
	128 pin QFP (FP-128)	HS2655ESHS1H		

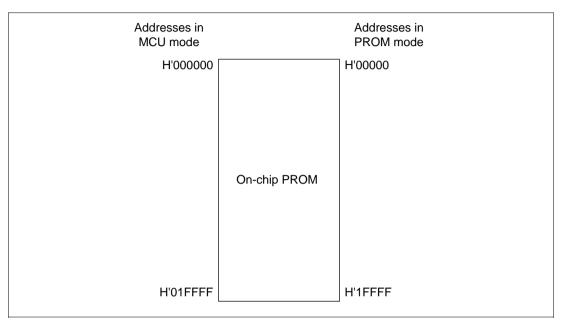


Figure 19-3 Memory Map in PROM Mode

19.5 Programming (H8S/2357ZTAT)

19.5.1 Overview

Table 19-6 shows how to select the program, verify, and program-inhibit modes in PROM mode.

Table 19-6 Mode Selection in PROM Mode

		Pins									
Mode	CE	OE	PGM	V _{PP}	V _{cc}	EO ₇ to EO ₀	EA ₁₆ to EA ₀				
Program	L	Н	L	V_{PP}	V_{cc}	Data input	Address input				
Verify	L	L	Н	V_{PP}	V_{cc}	Data output	Address input				
Program-inhibit	L	L	L	V_{PP}	V_{cc}	High impedance	Address input				
	L	Н	Н								
	Н	L	L	_							
	Н	Н	Н	_							

Legend

L : Low voltage level H : High voltage level V_{PP} : V_{PP} voltage level V_{CC} : V_{CC} voltage level

Programming and verification should be carried out using the same specifications as for the standard HN27C101 EPROM.

However, do not set the PROM programmer to page mode, as the H8S/2357 does not support page programming. A PROM programmer that only supports page programming cannot be used. When choosing a PROM programmer, check that it supports high-speed programming in byte units. Always set addresses within the range H'00000 to H'1FFFF.

19.5.2 Programming and Verification

An efficient, high-speed programming procedure can be used to program and verify PROM data. This procedure writes data quickly without subjecting the chip to voltage stress or sacrificing data reliability. It leaves the data H'FF in unused addresses. Figure 19-4 shows the basic high-speed programming flowchart. Tables 19-7 and 19-8 list the electrical characteristics of the chip during programming. Figure 19-5 shows a timing chart.

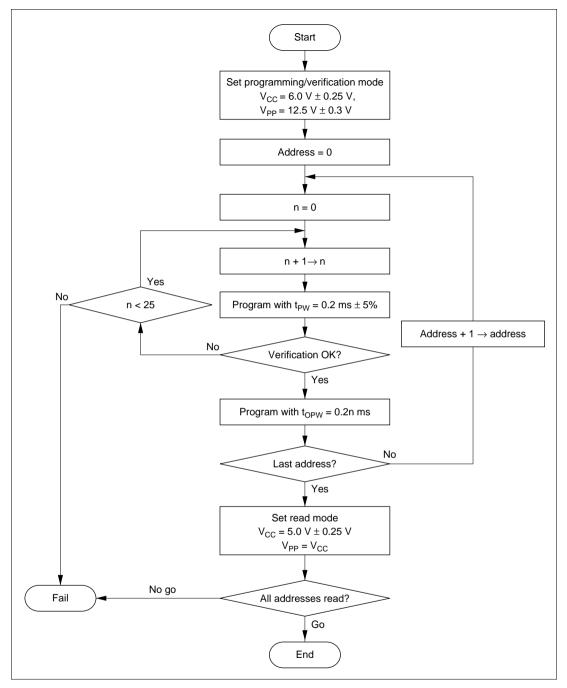


Figure 19-4 High-Speed Programming Flowchart

Table 19-7 DC Characteristics in PROM Mode $(When~V_{CC}=6.0~V\pm0.25~V,~V_{PP}=12.5~V\pm0.3~V,~V_{SS}=0~V,~T_a=25^{\circ}C\pm5^{\circ}C)$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Input high voltage	EO_7 to EO_0 , EA_{16} to EA_0 , \overline{OE} , \overline{CE} , \overline{PGM}	V _{IH}	2.4		V _{cc} + 0.3	V	
Input low voltage	EO ₇ to EO ₀ , EA ₁₆ to EA ₀ , OE, CE, PGM	V _{IL}	-0.3	_	0.8	V	
Output high voltage	EO ₇ to EO ₀	V_{OH}	2.4	_	_	V	$I_{OH} = -200 \ \mu A$
Output low voltage	EO ₇ to EO ₀	V _{OL}	_	_	0.45	V	I _{OL} = 1.6 mA
Input leakage current	EO_7 to EO_0 , EA_{16} to EA_0 , OE, CE , PGM		_	_	2	μΑ	V _{in} = 5.25 V/0.5 V
V _{cc} current		I _{cc}	_	_	40	mA	
V _{PP} current		I _{PP}	_	_	40	mA	

Table 19-8 AC Characteristics in PROM Mode (When $V_{CC}=6.0~V\pm0.25~V, V_{PP}=12.5~V\pm0.3~V, T_a=25^{\circ}C\pm5^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Address setup time	t _{AS}	2	_	_	μs	Figure 19-5*1
OE setup time	t _{OES}	2	_	_	μs	
Data setup time	t _{DS}	2	_	_	μs	
Address hold time	t _{AH}	0	_	_	μs	
Data hold time	t _{DH}	2	_	_	μs	
Data output disable time	t _{DF} *2	_	_	130	ns	
V _{PP} setup time	t _{VPS}	2	_	_	μs	
Programming pulse width	t _{PW}	0.19	0.20	0.21	ms	
PGM pulse width for overwrite programming	$t_{\text{OPW}}^{*^3}$	0.19	_	5.25	ms	
V _{cc} setup time	t _{vcs}	2	_	_	μs	
CE setup time	t _{CES}	2	_	_	μs	_
Data output delay time	t _{OE}	0	_	150	ns	

Notes: 1. Input pulse level: 0.8 V to 2.2 V Input rise time and fall time 20 ns

> Timing reference levels: Input: 1.0 V, 2.0 V Output: 0.8 V, 2.0 V

- 2. $t_{\rm DF}$ is defined to be when output has reached the open state, and the output level can no longer be referenced.
- 3. t_{OPW} is defined by the value shown in the flowchart.

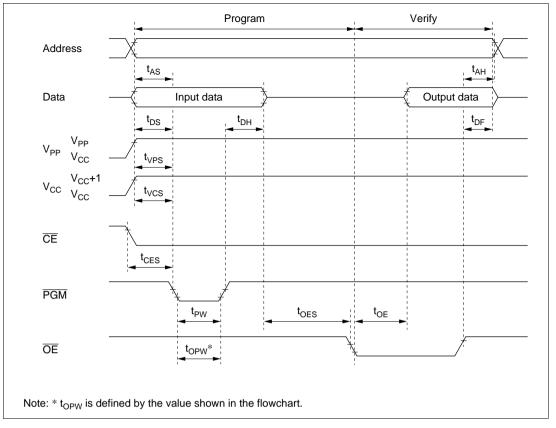


Figure 19-5 PROM Programming/Verification Timing

19.5.3 Programming Precautions

- Program using the specified voltages and timing.
 The programming voltage (V_{PP}) in PROM mode is 12.5 V.
 If the PROM programmer is set to Hitachi HN27C101 specifications, V_{PP} will be 12.5 V.
 Applied voltages in excess of the specified values can permanently destroy the MCU. Be particularly careful about the PROM programmer's overshoot characteristics.
- Before programming, check that the MCU is correctly mounted in the PROM programmer.
 Overcurrent damage to the MCU can result if the index marks on the PROM programmer, socket adapter, and MCU are not correctly aligned.
- Do not touch the socket adapter or MCU while programming. Touching either of these can cause contact faults and programming errors.
- The MCU cannot be programmed in page programming mode. Select the programming mode carefully.

 The size of the H8S/2357 PROM is 128 kbytes. Always set addresses within the range H'00000 to H'1FFFF. During programming, write H'FF to unused addresses to avoid verification errors.

19.5.4 Reliability of Programmed Data

An effective way to assure the data retention characteristics of the programmed chips is to bake them at 150°C, then screen them for data errors. This procedure quickly eliminates chips with PROM memory cells prone to early failure.

Figure 19-6 shows the recommended screening procedure.

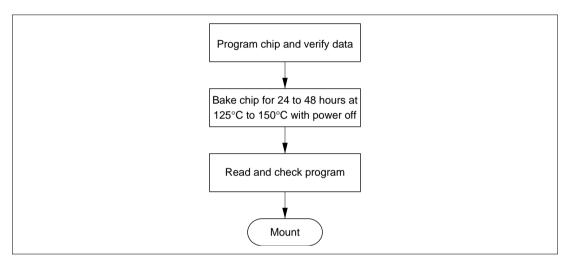


Figure 19-6 Recommended Screening Procedure

If a series of programming errors occurs while the same PROM programmer is being used, stop programming and check the PROM programmer and socket adapter for defects.

Please inform Hitachi of any abnormal conditions noted during or after programming or in screening of program data after high-temperature baking.

19.6 Overview of Flash Memory (H8S/2357F-ZTAT)

19.6.1 Features

The features of the flash memory are summarized below.

- Four flash memory operating modes
 - Program mode
 - Erase mode
 - Program-verify mode
 - Erase-verify mode
- Programming/erase methods

The flash memory is programmed 32 bytes at a time. Erasing is performed by block erase (in single-block units). When erasing multiple blocks, the individual blocks must be erased sequentially. Block erasing can be performed as required on 1-kbyte, 8-kbyte, 16-kbyte, 28-kbyte, and 32-kbyte blocks.

• Programming/erase times (5 V version)

The flash memory programming time is 10 ms (typ.) for simultaneous 32-byte programming, equivalent to 300 µs (typ.) per byte, and the erase time is 100 ms (typ.) per block.

Reprogramming capability

The flash memory can be reprogrammed up to 100 times.

• On-board programming modes

There are two modes in which flash memory can be programmed/erased/verified on-board:

- Boot mode
- User program mode
- Automatic bit rate adjustment

With data transfer in boot mode, the bit rate of the H8S/2357 Series chip can be automatically adjusted to match the transfer bit rate of the host.

• Flash memory emulation by RAM

Part of the RAM area can be overlapped onto flash memory, to emulate flash memory updates in real time.

Protect modes

There are three protect modes, hardware, software, and error protect, which allow protected status to be designated for flash memory program/erase/verify operations.

• Programmer mode

Flash memory can be programmed/erased in programmer mode, using a PROM programmer, as well as in on-board programming mode.

19.6.2 Block Diagram

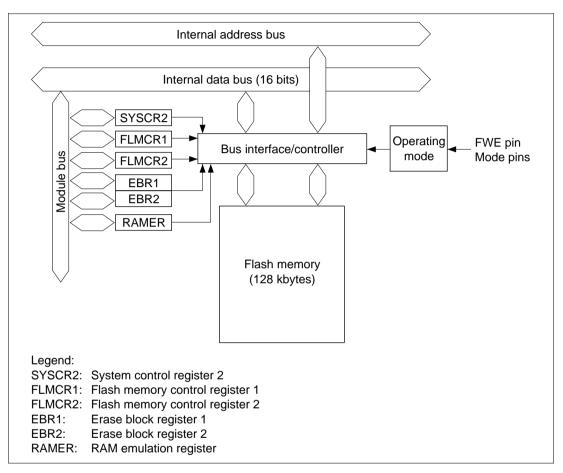


Figure 19-7 Block Diagram of Flash Memory

19.6.3 Flash Memory Operating Modes

Mode Transitions: When the mode pins and the FWE pin are set in the reset state and a reset-start is executed, the MCU enters one of the operating modes shown in figure 19-8. In user mode, flash memory can be read but not programmed or erased.

Flash memory can be programmed and erased in boot mode, user program mode, and programmer mode.

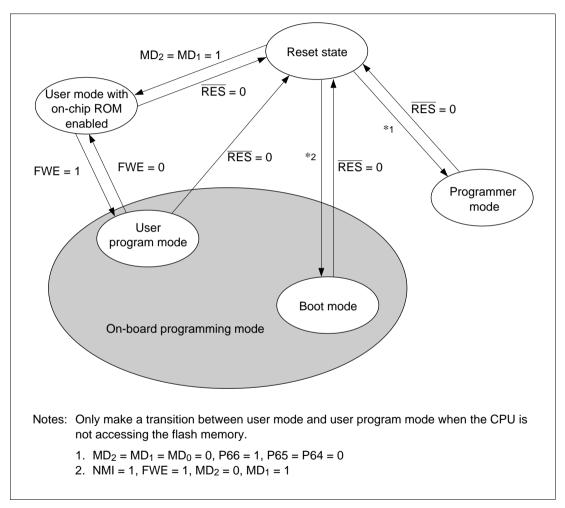


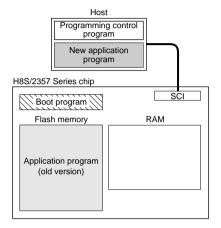
Figure 19-8 Flash Memory Mode Transitions

On-Board Programming Modes

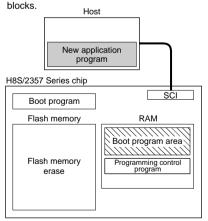
Boot mode

1. Initial state

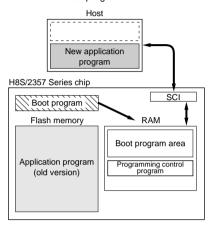
The old program version or data remains written in the flash memory. The user should prepare the programming control program and new application program beforehand in the host.



Flash memory initialization
 The erase program in the boot program area (in RAM) is executed, and the flash memory is initialized (to H'FF). In boot mode, entire flash memory erasure is performed, without regard to



Programming control program transfer
 When boot mode is entered, the boot program in
 the H8S/2357 chip (originally incorporated in the
 chip) is started and the programming control
 program in the host is transferred to RAM via SCI
 communication. The boot program required for
 flash memory erasing is automatically transferred
 to the RAM boot program area.



Writing new application program
 The programming control program transferred from the host to RAM is executed, and the new application program in the host is written into the flash memory.

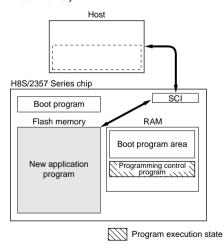
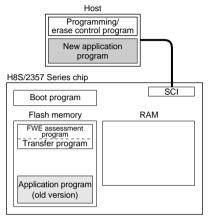


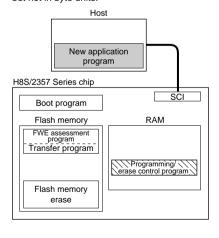
Figure 19-9 Boot Mode

User program mode

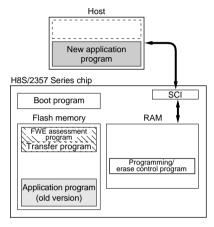
- 1. Initial state
 - (1) The FWE assessment program that confirms that the FWE pin has been driven high, and (2) the program that will transfer the programming/ erase control program to on-chip RAM should be written into the flash memory by the user beforehand. (3) The programming/erase control program should be prepared in the host or in the flash memory.



Flash memory initialization
 The programming/erase program in RAM is executed, and the flash memory is initialized (to H'FF). Erasing can be performed in block units, but not in byte units.



Programming/erase control program transfer When the FWE pin is driven high, user software confirms this fact, executes the transfer program in the flash memory, and transfers the programming/erase control program to RAM.



Writing new application program
 Next, the new application program in the host is
 written into the erased flash memory blocks. Do
 not write to unerased blocks.

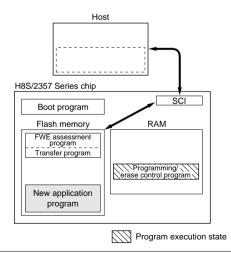


Figure 19-10 User Program Mode (Example)

Flash Memory Emulation in RAM: Emulation should be performed in user mode or user program mode. When the emulation block set in RAMER is accessed while the emulation function is being executed, data written in the overlap RAM is read.

• Reading Overlap Data in User Mode and User Program Mode

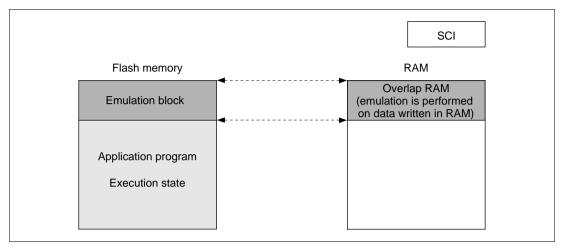


Figure 19-11 Reading Overlap Data in User Mode and User Program Mode

• Writing Overlap Data in User Program Mode

When overlap RAM data is confirmed, the RAMS bit is cleared, RAM overlap is released, and writes should actually be performed to the flash memory.

When the programming control program is transferred to RAM, ensure that the transfer destination and the overlap RAM do not overlap, as this will cause data in the overlap RAM to be rewritten.

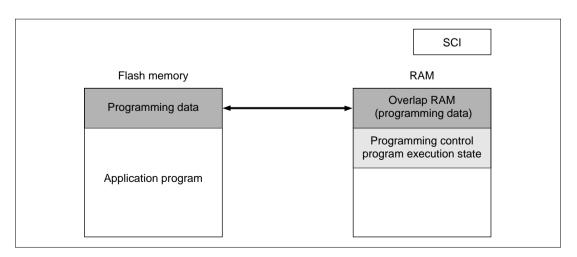


Figure 19-12 Writing Overlap Data in User Program Mode

Table 19-9 Differences between Boot Mode and User Program Mode

	Boot Mode	User Program Mode
Entire memory erase	Yes	Yes
Block erase	No	Yes
Programming control program*	Program/program-verify	Program/program-verify
		Erase/erase-verify

Note: * To be provided by the user, in accordance with the recommended algorithm.

Block Configuration: The flash memory is divided into two 32-kbyte blocks, two 8-kbyte blocks, one 16-kbyte block, one 28-kbyte block, and four 1-kbyte blocks.

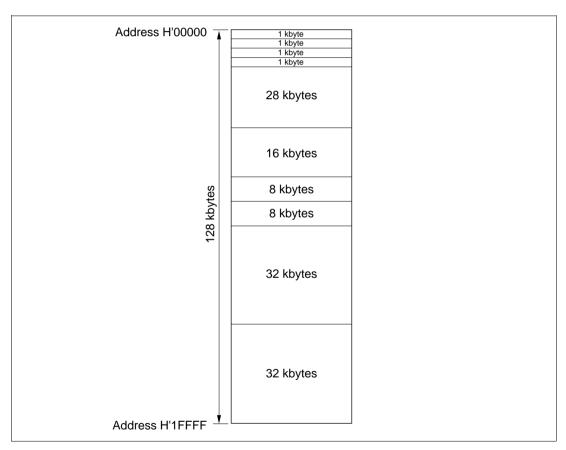


Figure 19-13 Flash Memory Block Configuration

19.6.4 Pin Configuration

The flash memory is controlled by means of the pins shown in table 19-10.

Table 19-10 Flash Memory Pins

Pin Name	Abbreviation	I/O	Function
Reset	RES	Input	Reset
Flash write enable	FWE	Input	Flash program/erase protection by hardware
Mode 2	MD_2	Input	Sets MCU operating mode
Mode 1	MD ₁	Input	Sets MCU operating mode
Mode 0	MD _o	Input	Sets MCU operating mode
Port 66	P66	Input	Sets MCU operating mode in programmer mode
Port 65	P65	Input	Sets MCU operating mode in programmer mode
Port 64	P64	Input	Sets MCU operating mode in programmer mode
Transmit data	TxD1	Output	Serial transmit data output
Receive data	RxD1	Input	Serial receive data input

19.6.5 Register Configuration

The registers used to control the on-chip flash memory when enabled are shown in table 19-11. In order for these registers to be accessed, the FLSHE bit must be set to 1 in SYSCR2 (except RAMER).

Table 19-11 Flash Memory Registers

Register Name	Abbreviation	R/W	Initial Value	Address*1
Flash memory control register 1	FLMCR1*6	R/W*3	H'00* ⁴	H'FF80*2
Flash memory control register 2	FLMCR2*6	R/W*3	H'00*5	H'FF81* ²
Erase block register 1	EBR1*6	R/W*3	H'00* ⁵	H'FF82* ²
Erase block register 2	EBR2*6	R/W*3	H'00* ⁵	H'FF83* ²
System control register 2	SYSCR2*7	R/W	H'00	H'FF42
RAM emulation register	RAMER	R/W	H'00	H'FEDB

Notes: 1. Lower 16 bits of the address.

- Flash memory registers are selected by the FLSHE bit in system control register 2 (SYSCR2).
- In modes in which the on-chip flash memory is disabled, a read will return H'00, and writes are invalid. Writes are also disabled when the FWE bit is cleared to 0 in FI MCR1.
- 4. When a high level is input to the FWE pin, the initial value is H'80.
- 5. When a low level is input to the FWE pin, or if a high level is input and the SWE bit in FLMCR1 is not set, these registers are initialized to H'00.
- 6. FLMCR1, FLMCR2, EBR1, and EBR2 are 8-bit registers. Only byte accesses are valid for these registers, the access requiring 2 states.
- 7. SYSCR2 is available only in the F-ZTAT version. In the mask ROM and ZTAT versions, this register cannot be written to and will return an undefined value if read.

19.7 Register Descriptions

19.7.1 Flash Memory Control Register 1 (FLMCR1)

Bit	7	6	5	4	3	2	1	0
	FWE	SWE			EV	PV	E	Р
Initial value	*	0	0	0	0	0	0	0
Read/Write	R	R/W	_	_	R/W	R/W	R/W	R/W

Note: * Determined by the state of the FWE pin.

FLMCR1 is an 8-bit register used for flash memory operating mode control. Program-verify mode or erase-verify mode is entered by setting SWE to 1 when FWE = 1. Program mode is entered by setting SWE to 1 when FWE = 1, then setting the PSU bit in FLMCR2, and finally setting the P bit. Erase mode is entered by setting SWE to 1 when FWE = 1, then setting the ESU bit in FLMCR2, and finally setting the E bit. FLMCR1 is initialized by a reset, and in hardware standby mode and software standby mode. Its initial value is H'80 when a high level is input to the FWE pin, and H'00 when a low level is input. When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

Writes to the SWE bit in FLMCR1 are enabled only when FWE = 1; writes to the EV and PV bits only when FWE=1 and SWE=1; writes to the E bit only when FWE = 1, SWE = 1, and ESU = 1; and writes to the P bit only when FWE = 1, SWE = 1, and PSU = 1.

Bit 7—Flash Write Enable Bit (FWE): Sets hardware protection against flash memory programming/erasing. See section 19.14, Flash Memory Programming and Erasing Precautions, before using this bit.

Bit 7 FWE	Description
0	When a low level is input to the FWE pin (hardware-protected state)
1	When a high level is input to the FWE pin

Bit 6—Software Write Enable Bit (SWE): Enables or disables flash memory programming. SWE should be set before setting bits ESU, PSU, EV, PV, E, P, and EB9 to EB0, and should not be cleared at the same time as these bits.

Bit 6 SWE	Description	
0	Writes disabled	(Initial value)
1	Writes enabled	
	[Setting condition]	
	When FWE = 1	

Bit 5 and 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—Erase-Verify (EV): Selects erase-verify mode transition or clearing. Do not set the SWE, ESU, PSU, PV, E, or P bit at the same time.

Bit 3 EV	Description	
0	Erase-verify mode cleared	(Initial value)
1	Transition to erase-verify mode	
	[Setting condition]	
	When FWE = 1 and SWE = 1	

Bit 2—Program-Verify (PV): Selects program-verify mode transition or clearing. Do not set the SWE, ESU, PSU, EV, E, or P bit at the same time.

Bit 2 PV	Description	
0	Program-verify mode cleared	(Initial value)
1	Transition to program-verify mode	
	[Setting condition]	
	When FWE = 1 and SWE = 1	

Bit 1—Erase (E): Selects erase mode transition or clearing. Do not set the SWE, ESU, PSU, EV, PV, or P bit at the same time.

Bit 1 E	Description	
0	Erase mode cleared	(Initial value)
1	Transition to erase mode	
	[Setting condition]	
	When FWE = 1, SWE = 1, and ESU = 1	

Bit 0—Program (P): Selects program mode transition or clearing. Do not set the SWE, PSU, ESU, EV, PV, or E bit at the same time.

Bit 0 P	Description	
0	Program mode cleared	(Initial value)
1	Transition to program mode	
	[Setting condition]	
	When FWE = 1, SWE = 1, and PSU = 1	

19.7.2 Flash Memory Control Register 2 (FLMCR2)

Bit	7	6	5	4	3	2	1	0
	FLER	_	_	_	_	_	ESU	PSU
Initial value	0	0	0	0	0	0	0	0
Read/Write	R			_	_	_	R/W	R/W

FLMCR2 is an 8-bit register that monitors the presence or absence of flash memory program/erase protection (error protection) and performs setup for flash memory program/erase mode. FLMCR2 is initialized to H'00 by a reset, and in hardware standby mode. The ESU and PSU bits are cleared to 0 in software standby mode, hardware protect mode, and software protect mode.

When on-chip flash memory is disabled, a read will return H'00.

Bit 7—Flash Memory Error (FLER): Indicates that an error has occurred during an operation on flash memory (programming or erasing). When FLER is set to 1, flash memory goes to the error-protection state.

Bit 7							
FLER	Description						
0	Flash memory is operating normally	(Initial value)					
	Flash memory program/erase protection (error protection) is disabled						
	[Clearing condition]						
	Reset or hardware standby mode						
1	An error has occurred during flash memory programming/erasing						
	Flash memory program/erase protection (error protection) is enabled						
	[Setting condition]						
	See section 19.10.3, Error Protection						

Bits 6 to 2—Reserved: These bits cannot be modified and are always read as 0.

Bit 1—Erase Setup (ESU): Prepares for a transition to erase mode. Set this bit to 1 before setting the E bit to 1 in FLMCR1. Do not set the SWE, PSU, EV, PV, E, or P bit at the same time.

Bit 1 ESU	Description	
0	Erase setup cleared	(Initial value)
1	Erase setup	
	[Setting condition]	
	When FWE = 1, and SWE = 1	

Bit 0—Program Setup (PSU): Prepares for a transition to program mode. Set this bit to 1 before setting the P bit to 1 in FLMCR1. Do not set the SWE, ESU, EV, PV, E, or P bit at the same time.

Bit 0
PSU
Description

0 Program setup cleared (Initial value)

1 Program setup
[Setting condition]
When FWE = 1, and SWE = 1

19.7.3 Erase Block Registers 1 and 2 (EBR1, EBR2)

Bit	7	6	5	4	3	2	1	0	
EBR1	_	_	_	_	_	_	EB9	EB8	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	_	_	_	_	_	_	R/W	R/W	
Bit	7	6	5	4	3	2	1	0	
EBR2	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	

EBR1 and EBR2 are registers that specify the flash memory erase area block by block; bits 1 and 2 in EBR1 and bits 7 to 0 in EBR2 are readable/writable bits. EBR1 and EBR2 are each initialized to H'00 by a reset, in hardware standby mode and software standby mode, when a low level is input to the FWE pin, and when a high level is input to the FWE pin and the SWE bit in FLMCR1 is not set. When a bit in EBR1 or EBR2 is set, the corresponding block can be erased. Other blocks are erase-protected. Set only one bit in EBR1 or EBR2 (more than one bit cannot be set). When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

The flash memory block configuration is shown in table 19-12.

Table 19-12 Flash Memory Erase Blocks

Block (Size)	Address
EB0 (1 kbyte)	H'000000 to H'0003FF
EB1 (1 kbyte)	H'000400 to H'0007FF
EB2 (1 kbyte)	H'000800 to H'000BFF
EB3 (1 kbyte)	H'000C00 to H'000FFF
EB4 (28 kbytes)	H'001000 to H'007FFF
EB5 (16 kbytes)	H'008000 to H'00BFFF
EB6 (8 kbytes)	H'00C000 to H'00DFFF
EB7 (8 kbytes)	H'00E000 to H'00FFFF
EB8 (32 kbytes)	H'010000 to H'017FFF
EB9 (32 kbytes)	H'018000 to H'01FFFF

19.7.4 System Control Register 2 (SYSCR2)

Bit	7	6	5	4	3	2	1	0	
		_		_	FLSHE	_]
Initial value	0	0	0	0	0	0	0	0	-
Read/Write	_	_	_	_	R/W	_	_	_	

SYSCR2 is an 8-bit readable/writable register that controls on-chip flash memory (in F-ZTAT versions).

SYSCR2 is initialized to H'00 by a reset and in hardware standby mode.

SYSCR2 is available only in the F-ZTAT version. In the mask ROM and ZTAT versions, this register cannot be written to and will return an undefined value if read.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—Flash Memory Control Register Enable (FLSHE): Controls CPU access to the flash memory control registers (FLMCR1, FLMCR2, EBR1, and EBR2). Setting the FLSHE bit to 1 enables read/write access to the flash memory control registers. If FLSHE is cleared to 0, the flash memory control registers are deselected. In this case, the flash memory control register contents are retained.

Bit 3 FLSHE	Description	
0	Flash control registers deselected in area H'FFFFC8 to H'FFFFCB	(Initial value)
1	Flash control registers selected in area H'FFFFC8 to H'FFFFCB	

Bits 2 to 0—Reserved: These bits cannot be modified and are always read as 0.

19.7.5 RAM Emulation Register (RAMER)

RAMER specifies the area of flash memory to be overlapped with part of RAM when emulating real-time flash memory programming. RAMER is initialized to H'00 by a reset and in hardware standby mode. It is not initialized in software standby mode. RAMER settings should be made in user mode or user program mode.

Flash memory area divisions are shown in table 19-13. To ensure correct operation of the emulation function, the ROM for which RAM emulation is performed should not be accessed immediately after this register has been modified. Normal execution of an access immediately after register modification is not guaranteed.

Bit:	7	6	5	4	3	2	1	0
		_	_	_	_	RAMS	RAM1	RAM0
Initial value:	0	0	0	0	0	0	0	0
R/W:	_	_	_	_	_	R/W	R/W	R/W

Bits 7 to 3—Reserved: These bits are always read as 0.

Bit 2—RAM Select (RAMS): Specifies selection or non-selection of flash memory emulation in RAM. When RAMS = 1, all flash memory block are program/erase-protected.

Bit 2 RAMS	Description	
0	Emulation not selected	(Initial value)
	Program/erase-protection of all flash memory blocks is disabled	
1	Emulation selected	
	Program/erase-protection of all flash memory blocks is enabled	

Bits 1 and 0—Flash Memory Area Selection (RAM1, RAM0): These bits are used together with bit 2 to select the flash memory area to be overlapped with RAM. (See table 19-13.)

Table 19-13 Flash Memory Area Divisions

Addresses	Block Name	RAMS	RAM1	RAM0	
H'FFDC00-H'FFDFFF	RAM area 1 kbyte	0	*	*	
H'000000-H'0003FF	EB0 (1 kbyte)	1	0	0	
H'000400-H'0007FF	EB1 (1 kbyte)	1	0	1	
H'000800-H'000BFF	EB2 (1 kbyte)	1	1	0	
H'000C00-H'000FFF	EB3 (1 kbyte)	1	1	1	

^{* ·} Don't care

19.8 On-Board Programming Modes

When pins are set to on-board programming mode, program/erase/verify operations can be performed on the on-chip flash memory. There are two on-board programming modes: boot mode and user program mode. The pin settings for transition to each of these modes are shown in table 19-14. For a diagram of the transitions to the various flash memory modes, see figure 19-8.

Table 19-14 Setting On-Board Programming Modes

_	_			
N	л	^	~	

Mode Name	CPU Operating Mode	FWE	MD_2	MD_1	MD_0
Boot mode	Advanced expanded mode with on-chip ROM enabled	1	0	1	0
	Advanced single-chip mode				1
User program mode*	Advanced expanded mode with on-chip ROM enabled	1	1	1	0
	Advanced single-chip mode				1

Note: * Normally, user mode should be used. Set FWE to 1 to make a transition to user program mode before performing a program/erase/verify operation.

19.8.1 Boot Mode

When boot mode is used, the flash memory programming control program must be prepared in the host beforehand. The channel 1 SCI to be used is set to asynchronous mode.

When a reset-start is executed after the H8S/2357 MCU's pins have been set to boot mode, the boot program built into the MCU is started and the programming control program prepared in the host is serially transmitted to the MCU via the SCI. In the MCU, the programming control program received via the SCI is written into the programming control program area in on-chip RAM. After the transfer is completed, control branches to the start address of the programming control program area and the programming control program execution state is entered (flash memory programming is performed).

The transferred programming control program must therefore include coding that follows the programming algorithm given later.

The system configuration in boot mode is shown in figure 19-14, and the boot program mode execution procedure in figure 19-15.

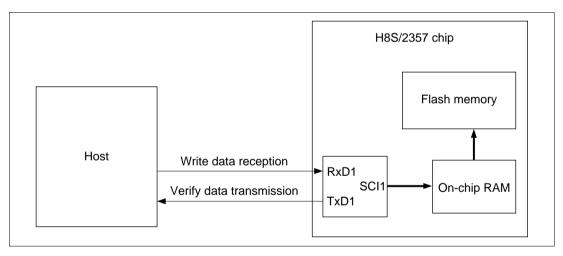


Figure 19-14 System Configuration in Boot Mode

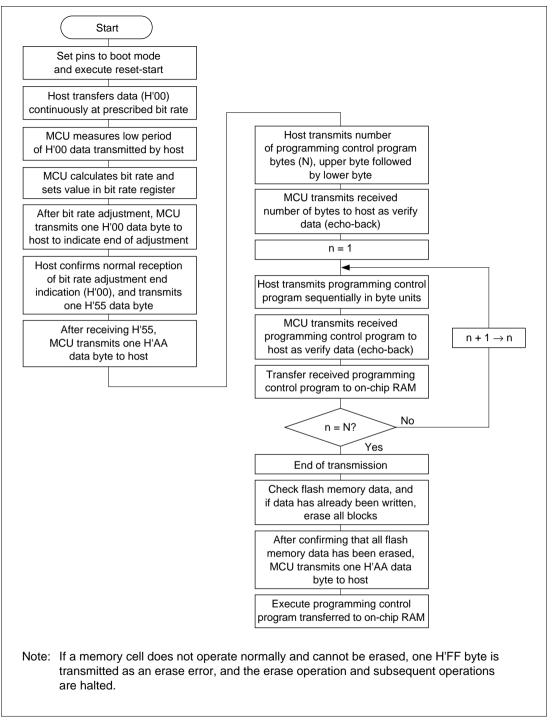


Figure 19-15 Boot Mode Execution Procedure

Automatic SCI Bit Rate Adjustment

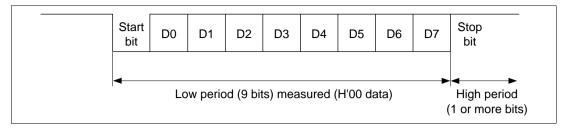


Figure 19-16 Automatic SCI Bit Rate Adjustment

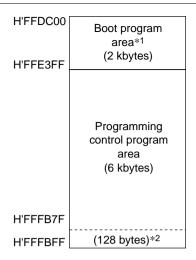
When boot mode is initiated, the H8S/2357 MCU measures the low period of the asynchronous SCI communication data (H'00) transmitted continuously from the host. The SCI transmit/receive format should be set as follows: 8-bit data, 1 stop bit, no parity. The MCU calculates the bit rate of the transmission from the host from the measured low period, and transmits one H'00 byte to the host to indicate the end of bit rate adjustment. The host should confirm that this adjustment end indication (H'00) has been received normally, and transmit one H'55 byte to the MCU. If reception cannot be performed normally, initiate boot mode again (reset), and repeat the above operations. Depending on the host's transmission bit rate and the MCU's system clock frequency, there will be a discrepancy between the bit rates of the host and the MCU. To ensure correct SCI operation, the host's transfer bit rate should be set to (4800, or 9600) bps.

Table 19-15 shows typical host transfer bit rates and system clock frequencies for which automatic adjustment of the MCU's bit rate is possible. The boot program should be executed within this system clock range.

Table 19-15 System Clock Frequencies for which Automatic Adjustment of H8S/2357 Bit Rate is Possible

Host Bit Rate	System Clock Frequency for which Automatic Adjustment of H8S/2357 Bit Rate is Possible
9600 bps	8 MHz to 20 MHz
4800 bps	4 MHz to 20 MHz

On-Chip RAM Area Divisions in Boot Mode: In boot mode, the 2 kbytes area from H'FFDC00 to H'FFE3FF is reserved for use by the boot program, as shown in figure 19-17. The area to which the programming control program is transferred is H'FFE400 to H'FFFB7F. The boot program area can be used when the programming control program transferred into RAM enters the execution state. A stack area should be set up as required.



Note: 1. The boot program area cannot be used until a transition is made to the execution state for the programming control program transferred to RAM. Note that the boot program remains stored in this area after a branch is made to the programming control program.

2. The area from H'FFFB80 to H'FFFBFF (128 bytes) is used by the boot program.

The area from H'FFE400 to H'FFFB7F can be used by the programming control program.

Figure 19-17 RAM Areas in Boot Mode

Notes on Use of User Mode:

- When the chip comes out of reset in boot mode, it measures the low-level period of the input at
 the SCI's RxD1 pin. The reset should end with RxD1 high. After the reset ends, it takes
 approximately 100 states before the chip is ready to measure the low-level period of the RxD1
 pin.
- In boot mode, if any data has been programmed into the flash memory (if all data is not 1), all flash memory blocks are erased. Boot mode is for use when user program mode is unavailable, such as the first time on-board programming is performed, or if the program activated in user program mode is accidentally erased.
- Interrupts cannot be used while the flash memory is being programmed or erased.
- The RxD1 and TxD1 pins should be pulled up on the board.
- Before branching to the programming control program (RAM area H'FFE400), the chip terminates transmit and receive operations by the on-chip SCI (channel 1) (by clearing the RE and TE bits in SCR to 0), but the adjusted bit rate value remains set in BRR. The transmit data output pin, TxD1, goes to the high-level output state (P31DDR = 1, P31DR = 1).

The contents of the CPU's internal general registers are undefined at this time, so these registers must be initialized immediately after branching to the programming control program. In particular, since the stack pointer (SP) is used implicitly in subroutine calls, etc., a stack area must be specified for use by the programming control program.

Initial settings must also be made for the other on-chip registers.

- Boot mode can be entered by making the pin settings shown in table 19-14 and executing a reset-start.
 - Boot mode can be cleared by driving the reset pin low, waiting at least 20 states, then setting the FWE pin and mode pins, and executing reset release*¹. Boot mode can also be cleared by a WDT overflow reset.
 - Do not change the mode pin input levels in boot mode, and do not drive the FWE pin low while the boot program is being executed or while flash memory is being programmed or erased*².
- If the mode pin input levels are changed (for example, from low to high) during a reset, the state of ports with multiplexed address functions and bus control output pins (AS, RD, HWR) will change according to the change in the microcomputer's operating mode*³.
 - Therefore, care must be taken to make pin settings to prevent these pins from becoming output signal pins during a reset, or to prevent collision with signals outside the microcomputer.
- Notes: 1. Mode pins and FWE pin input must satisfy the mode programming setup time ($t_{MDS} = 200 \text{ ns}$) with respect to the reset release timing, as shown in figures 19-33 to 19-35.
 - 2. For further information on FWE application and disconnection, see section 19.14, Flash Memory Programming and Erasing Precautions.
 - 3. See appendix D, Pin States.

19.8.2 User Program Mode

When set to user program mode, the chip can program and erase its flash memory by executing a user program/erase control program. Therefore, on-board reprogramming of the on-chip flash memory can be carried out by providing on-board means of FWE control and supply of programming data, and storing a program/erase control program in part of the program area as necessary.

To select user program mode, select a mode that enables the on-chip flash memory (mode 6 or 7), and apply a high level to the FWE pin. In this mode, on-chip supporting modules other than flash memory operate as they normally would in modes 6 and 7.

The flash memory itself cannot be read while the SWE bit is set to 1 to perform programming or erasing, so the control program that performs programming and erasing should be run in on-chip RAM or external memory.

Figure 19-18 shows the procedure for executing the program/erase control program when transferred to on-chip RAM.

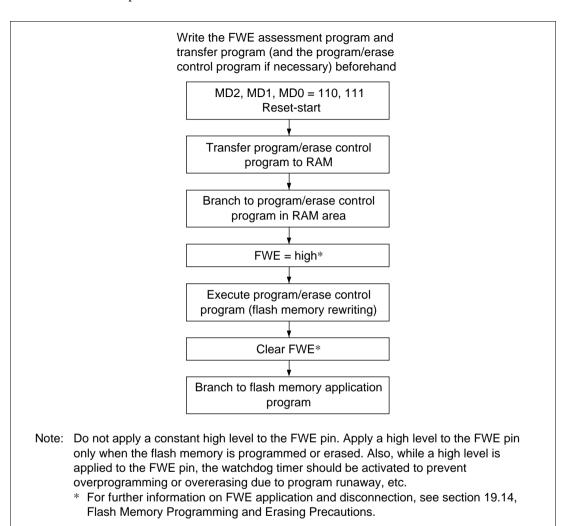


Figure 19-18 User Program Mode Execution Procedure

19.9 Programming/Erasing Flash Memory

In the on-board programming modes, flash memory programming and erasing is performed by software, using the CPU. There are four flash memory operating modes: program mode, erase mode, program-verify mode, and erase-verify mode. Transitions to these modes can be made by setting the PSU and ESU bits in FLMCR2, and the P, E, PV, and EV bits in FLMCR1.

The flash memory cannot be read while being programmed or erased. Therefore, the program that controls flash memory programming/erasing (the programming control program) should be located and executed in on-chip RAM or external memory.

- Notes: 1. Operation is not guaranteed if setting/resetting of the SWE, EV, PV, E, and P bits in FLMCR1, and the ESU and PSU bits in FLMCR2, is executed by a program in flash memory.
 - 2. When programming or erasing, set FWE to 1 (programming/erasing will not be executed if FWE = 0).
 - 3. Perform programming in the erased state. Do not perform additional programming on previously programmed addresses.

19.9.1 Program Mode

Follow the procedure shown in the program/program-verify flowchart in figure 19-19 to write data or programs to flash memory. Performing program operations according to this flowchart will enable data or programs to be written to flash memory without subjecting the device to voltage stress or sacrificing program data reliability. Programming should be carried out 32 bytes at a time.

The wait times $(x, y, z, \alpha, \beta, \gamma, \epsilon, \eta)$ after bits are set or cleared in flash memory control registers 1 and 2 (FLMCR1, FLMCR2) and the maximum number of programming operations (N) are shown in table 22.42 in section 22.7.6, Flash Memory Characteristics.

Following the elapse of (x) µs or more after the SWE bit is set to 1 in flash memory control register 1 (FLMCR1), 32-byte program data is stored in the program data area and reprogram data area, and the 32-byte data in the reprogram data area written consecutively to the write addresses. The lower 8 bits of the first address written to must be H'00, H'20, H'40, H'60, H'80, H'A0, H'C0, or H'E0. Thirty-two consecutive byte data transfers are performed. The program address and program data are latched in the flash memory. A 32-byte data transfer must be performed even if writing fewer than 32 bytes; in this case, H'FF data must be written to the extra addresses.

Next, the watchdog timer is set to prevent overprogramming in the event of program runaway, etc. Set a value greater than $(y + z + \alpha + \beta)$ µs as the WDT overflow period. After this, preparation for program mode (program setup) is carried out by setting the PSU bit in FLMCR2, and after the elapse of (y) µs or more, the operating mode is switched to program mode by setting the P bit in

FLMCR1. The time during which the P bit is set is the flash memory programming time. Make a program setting so that the time for one programming operation is within the range of (z) µs.

19.9.2 Program-Verify Mode

In program-verify mode, the data written in program mode is read to check whether it has been correctly written in the flash memory.

After the elapse of a given programming time, the programming mode is exited (the P bit in FLMCR1 is cleared to 0, then the PSU bit in FLMCR2 is cleared to 0 at least (α) μ s later). Next, the watchdog timer is cleared after the elapse of (β) μ s or more, and the operating mode is switched to program-verify mode by setting the PV bit in FLMCR1. Before reading in program-verify mode, a dummy write of H'FF data should be made to the addresses to be read. The dummy write should be executed after the elapse of (γ) μ s or more. When the flash memory is read in this state (verify data is read in 16-bit units), the data at the latched address is read. Wait at least (ϵ) μ s after the dummy write before performing this read operation. Next, the originally written data is compared with the verify data, and reprogram data is computed (see figure 19-19) and transferred to the reprogram data area. After 32 bytes of data have been verified, exit program-verify mode, wait for at least (η) μ s, then clear the SWE bit in FLMCR1 to 0. If reprogramming is necessary, set program mode again, and repeat the program/program-verify sequence as before. However, ensure that the program/program-verify sequence is not repeated more than (N) times on the same bits.

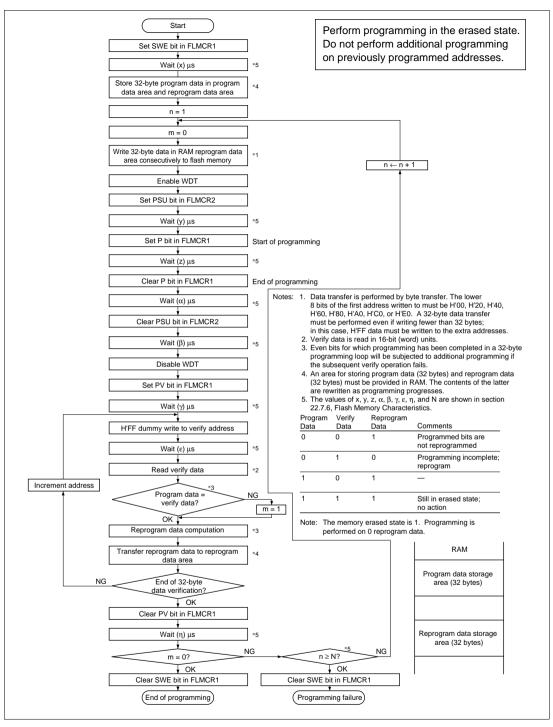


Figure 19-19 Program/Program-Verify Flowchart

19.9.3 Erase Mode

Flash memory erasing should be performed block by block following the procedure shown in the erase/erase-verify flowchart (single-block erase) shown in figure 19-20.

The wait times $(x, y, z, \alpha, \beta, \gamma, \epsilon, \eta)$ after bits are set or cleared in flash memory control registers 1 and 2 (FLMCR1, FLMCR2) and the maximum number of programming operations (N) are shown in table 22.42 in section 22.7.6, Flash Memory Characteristics.

To perform data or program erasure, make a 1 bit setting for the flash memory area to be erased in erase block register 1 or 2 (EBR1 or EBR2) at least (x) μ s after setting the SWE bit to 1 in flash memory control register 1 (FLMCR1). Next, the watchdog timer is set to prevent overerasing in the event of program runaway, etc. Set a value greater than $(y + z + \alpha + \beta)$ μ s as the WDT overflow period. After this, preparation for erase mode (erase setup) is carried out by setting the ESU bit in FLMCR2, and after the elapse of (y) μ s or more, the operating mode is switched to erase mode by setting the E bit in FLMCR1. The time during which the E bit is set is the flash memory erase time. Ensure that the erase time does not exceed (z) ms.

Note: With flash memory erasing, preprogramming (setting all data in the memory to be erased to 0) is not necessary before starting the erase procedure.

19.9.4 Erase-Verify Mode

In erase-verify mode, data is read after memory has been erased to check whether it has been correctly erased.

After the elapse of the erase time, erase mode is exited (the E bit in FLMCR1 is cleared to 0, then the ESU bit in FLMCR2 is cleared to 0 at least (α) μ s later), the watchdog timer is cleared after the elapse of (β) μ s or more, and the operating mode is switched to erase-verify mode by setting the EV bit in FLMCR1. Before reading in erase-verify mode, a dummy write of H'FF data should be made to the addresses to be read. The dummy write should be executed after the elapse of (γ) μ s or more. When the flash memory is read in this state (verify data is read in 16-bit units), the data at the latched address is read. Wait at least (ϵ) μ s after the dummy write before performing this read operation. If the read data has been erased (all 1), a dummy write is performed to the next address, and erase-verify is performed. If the read data has not been erased, set erase mode again, and repeat the erase/erase-verify sequence in the same way. However, ensure that the erase/erase-verify sequence is not repeated more than (N) times. When verification is completed, exit erase-verify mode, and wait for at least (η) μ s. If erasure has been completed on all the erase blocks, clear the SWE bit in FLMCR1 to 0. If there are any unerased blocks, make a 1 bit setting in EBR1 or EBR2 for the flash memory area to be erased, and repeat the erase/erase-verify sequence in the same way.

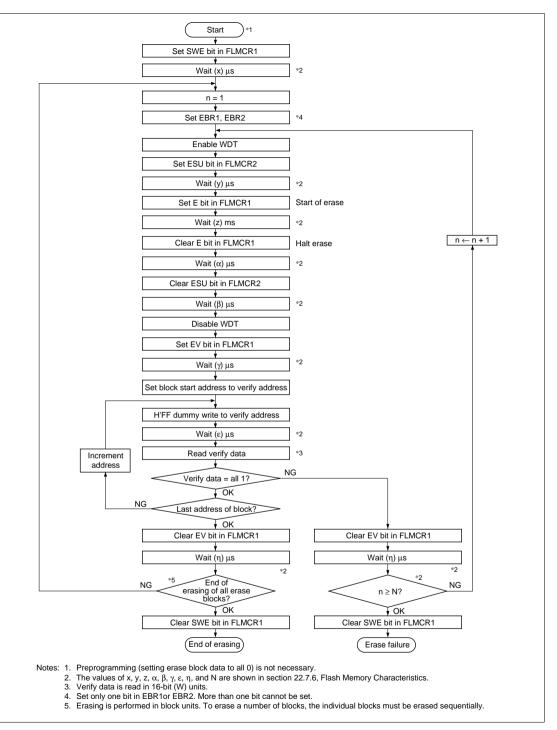


Figure 19-20 Erase/Erase-Verify Flowchart (Single-Block Erase)

19.10 Flash Memory Protection

There are three kinds of flash memory program/erase protection: hardware protection, software protection, and error protection.

19.10.1 Hardware Protection

Hardware protection refers to a state in which programming/erasing of flash memory is forcibly disabled or aborted. Hardware protection is reset by settings in flash memory control registers 1 and 2 (FLMCR1, FLMCR2) and erase block registers 1 and 2 (EBR1, EBR2). (See table 19-16.)

Table 19-16 Hardware Protection

		Fur	nctions
Item	Description	Program	Erase
FWE pin protection	When a low level is input to the FWE pin, FLMCR1, FLMCR2 (excluding the FLER bit), EBR1, and EBR2 are initialized, and the program/erase-protected state is entered.	Yes	Yes
Reset/standby protection	 In a reset (including a WDT overflow reset) and in standby mode, FLMCR1, FLMCR2, EBR1, and EBR2 are initialized, and the program/erase-protected state is entered. 	Yes	Yes
	In a reset via the RES pin, the reset state is not entered unless the RES pin is held low until oscillation stabilizes after powering on. In the case of a reset during operation, hold the RES pin low for the RES pulse width specified in the AC Characteristics section.		

19.10.2 Software Protection

Software protection can be implemented by setting the SWE bit in FLMCR1, erase block registers 1 and 2 (EBR1, EBR2), and the RAMS bit in RAMER. When software protection is in effect, setting the P or E bit in flash memory control register 1 (FLMCR1) does not cause a transition to program mode or erase mode. (See table 19-17.)

Table 19-17 Software Protection

		Functions		
Item	Description	Program	Erase	
SWE bit protection	Clearing the SWE bit to 0 in FLMCR1 sets the program/erase-protected state for all blocks.	Yes	Yes	
	(Execute in on-chip RAM or external memory.)			
Block specification protection	 Erase protection can be set for individual blocks by settings in erase block registers 1 and 2 (EBR1, EBR2). 	_	Yes	
	• Setting EBR1 and EBR2 to H'00 places all blocks in the erase-protected state.			
Emulation protection	 Setting the RAMS bit to 1 in the RAM emulation register (RAMER) places all blocks in the program/erase-protected state. 	Yes	Yes	

19.10.3 Error Protection

In error protection, an error is detected when MCU runaway occurs during flash memory programming/erasing, or operation is not performed in accordance with the program/erase algorithm, and the program/erase operation is aborted. Aborting the program/erase operation prevents damage to the flash memory due to overprogramming or overerasing.

If the MCU malfunctions during flash memory programming/erasing, the FLER bit is set to 1 in FLMCR2 and the error protection state is entered. The FLMCR1, FLMCR2, EBR1, and EBR2 settings are retained, but program mode or erase mode is aborted at the point at which the error occurred. Program mode or erase mode cannot be re-entered by re-setting the P or E bit. However, PV and EV bit setting is enabled, and a transition can be made to verify mode.

FLER bit setting conditions are as follows:

- When flash memory is read during programming/erasing (including a vector read or instruction fetch)
- Immediately after exception handling (excluding a reset) during programming/erasing
- When a SLEEP instruction (including software standby) is executed during programming/erasing
- When the CPU loses the bus during programming/erasing

Error protection is released only by a reset and in hardware standby mode.

Figure 19-21 shows the flash memory state transition diagram.

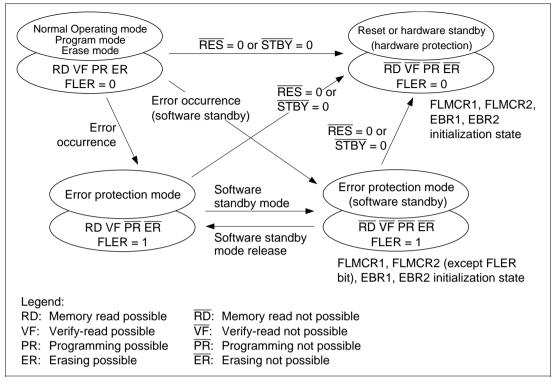


Figure 19-21 Flash Memory State Transitions

19.11 Flash Memory Emulation in RAM

19.11.1 Emulation in RAM

Making a setting in the RAM emulation register (RAMER) enables part of RAM to be overlapped onto the flash memory area so that data to be written to flash memory can be emulated in RAM in real time. After the RAMER setting has been made, accesses can be made from the flash memory area or the RAM area overlapping flash memory. Emulation can be performed in user mode and user program mode. Figure 19-22 shows an example of emulation of real-time flash memory programming.

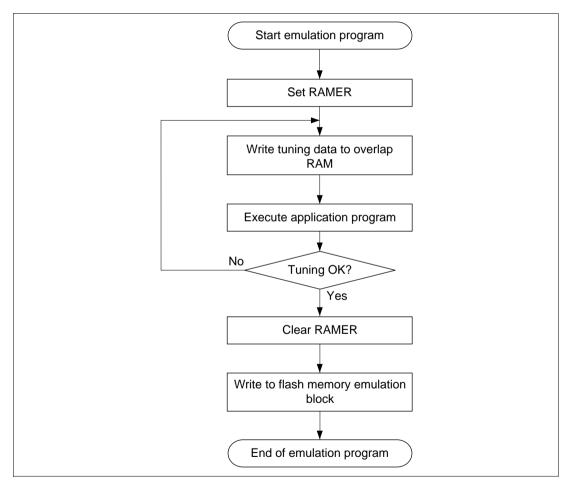


Figure 19-22 Flowchart for Flash Memory Emulation in RAM

19.11.2 RAM Overlap

An example in which flash memory block area EB1 is overlapped is shown below.

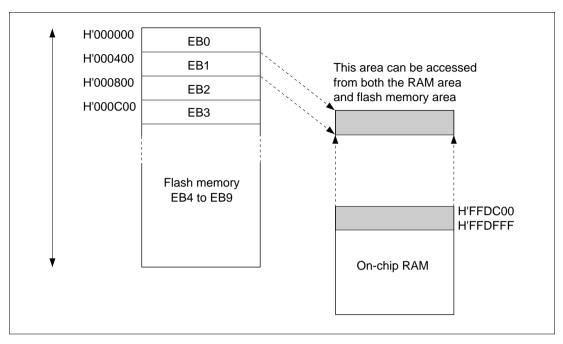


Figure 19.23 Example of RAM Overlap Operation

Example in Which Flash Memory Block Area (EB4) is Overlapped

- 1. Set bits RAMS, RAM1, and RAM0 in RAMER to 1, 0, 1, to overlap part of RAM onto the area (EB1) for which real-time programming is required.
- 2. Real-time programming is performed using the overlapping RAM.
- 3. After the program data has been confirmed, the RAMS bit is cleared, releasing RAM overlap.
- 4. The data written in the overlapping RAM is written into the flash memory space (EB1).
- Notes: 1. When the RAMS bit is set to 1, program/erase protection is enabled for all blocks regardless of the value of RAM1 and RAM0 (emulation protection). In this state, setting the P or E bit in flash memory control register 1 (FLMCR1) will not cause a transition to program mode or erase mode. When actually programming a flash memory area, the RAMS bit should be cleared to 0.
 - 2. A RAM area cannot be erased by execution of software in accordance with the erase algorithm while flash memory emulation in RAM is being used.
 - 3. Block area EB0 includes the vector table. When performing RAM emulation, the vector table is needed by the overlap RAM.

19.12 Interrupt Handling when Programming/Erasing Flash Memory

All interrupts, including NMI interrupt is disabled when flash memory is being programmed or erased (when the P or E bit is set in FLMCR1), and while the boot program is executing in boot mode*¹, to give priority to the program or erase operation. There are three reasons for this:

- 1. Interrupt during programming or erasing might cause a violation of the programming or erasing algorithm, with the result that normal operation could not be assured.
- 2. In the interrupt exception handling sequence during programming or erasing, the vector would not be read correctly*², possibly resulting in MCU runaway.
- 3. If interrupt occurred during boot program execution, it would not be possible to execute the normal boot mode sequence.

For these reasons, in on-board programming mode alone there are conditions for disabling interrupt, as an exception to the general rule. However, this provision does not guarantee normal erasing and programming or MCU operation. All requests, including NMI interrupt, must therefore be restricted inside and outside the MCU when programming or erasing flash memory. NMI interrupt is also disabled in the error-protection state while the P or E bit remains set in FLMCR1.

- Notes: 1. Interrupt requests must be disabled inside and outside the MCU until the programming control program has completed programming.
 - 2. The vector may not be read correctly in this case for the following two reasons:
 - If flash memory is read while being programmed or erased (while the P or E bit is set in FLMCR1), correct read data will not be obtained (undetermined values will be returned).
 - If the interrupt entry in the vector table has not been programmed yet, interrupt exception handling will not be executed correctly.

19.13 Flash Memory Programmer Mode

19.13.1 Programmer Mode Setting

Programs and data can be written and erased in programmer mode as well as in the on-board programming modes. In programmer mode, the on-chip ROM can be freely programmed using a PROM programmer that supports Hitachi microcomputer device types with 128-kbyte on-chip flash memory. Flash memory read mode, auto-program mode, auto-erase mode, and status read mode are supported with this device type. In auto-program mode, auto-erase mode, and status read mode, a status polling procedure is used, and in status read mode, detailed internal signals are output after execution of an auto-program or auto-erase operation.

Table 19-18 shows programmer mode pin settings.

Table 19-18 Programmer Mode Pin Settings

Pin Names	Settings/External Circuit Connection
Mode pins: MD ₂ , MD ₁ , MD ₀	Low-level input
Mode setting pins: P66, P65, P64	High-level input to P66, low-level input to P65 and P64
FWE pin	High-level input (in auto-program and auto-erase modes)
STBY pin	High-level input (do not select hardware standby mode)
RES pin	Power-on reset circuit
XTAL, EXTAL pins	Oscillator circuit
Other pins requiring setting: P51, P25	High-level input to P51 and P25

19.13.2 Socket Adapters and Memory Map

In programmer mode, a socket adapter is mounted on the PROM programmer to match the package concerned. Socket adapters are available for each writer manufacturer supporting the Hitachi microcomputer device type with 128-kbyte on-chip flash memory.

Figure 19-24 shows the memory map in programmer mode. For pin names in programmer mode, see section 1.3.2, Pin Functions in Each Operating Mode.

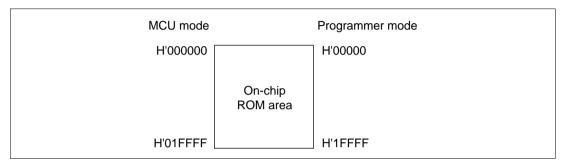


Figure 19-24 Memory Map in Programmer Mode

19.13.3 Programmer Mode Operation

Table 19-19 shows how the different operating modes are set when using programmer mode, and table 19-20 lists the commands used in programmer mode. Details of each mode are given below.

- Memory Read Mode
 Memory read mode supports byte reads.
- Auto-Program Mode
 Auto-program mode supports programming of 128 bytes at a time. Status polling is used to confirm the end of auto-programming.
- Auto-Erase Mode

Auto-erase mode supports automatic erasing of the entire flash memory. Status polling is used to confirm the end of auto-erasing.

Status Read Mode

Status polling is used for auto-programming and auto-erasing, and normal termination can be confirmed by reading the I/O6 signal. In status read mode, error information is output if an error occurs.

Table 19-19 Settings for Each Operating Mode in Programmer Mode

Pin Names

Mode	FWE	CE	OE	WE	I/O0 to I/O7	A0 to A16
Read	H or L	L	L	Н	Data output	Ain
Output disable	H or L	L	Н	Н	Hi-z	X
Command write	H or L*3	L	Н	L	Data input	Ain*2
Chip disable*1	H or L	Н	Х	Х	Hi-z	Х

Legend:

H: High level

L: Low level

Hi-z: High impedance X: Don't care

Notes: 1. Chip disable is not a standby state; internally, it is an operation state.

- 2. Ain indicates that there is also address input in auto-program mode.
- 3. For command writes when making a transition to auto-program or auto-erase mode, input a high level to the FWE pin.

Table 19-20 Programmer Mode Commands

	Number	1st Cycle				2nd Cycle		
Command Name	of Cycles	Mode	Address	Data	Mode	Address	Data	
Memory read mode	1 + n	Write	Х	H'00	Read	RA	Dout	
Auto-program mode	129	Write	Х	H'40	Write	PA	Din	
Auto-erase mode	2	Write	Χ	H'20	Write	Χ	H'20	
Status read mode	2	Write	Х	H'71	Write	Х	H'71	

Legend:

RA: Read address

PA: Program address

Notes: 1. In auto-program mode. 129 cycles are required for command writing by a simultaneous 128-byte write.

2. In memory read mode, the number of cycles depends on the number of address write cycles (n).

19.13.4 Memory Read Mode

- After the end of an auto-program, auto-erase, or status read operation, the command wait state
 is entered. To read memory contents, a transition must be made to memory read mode by
 means of a command write before the read is executed.
- Command writes can be performed in memory read mode, just as in the command wait state.
- Once memory read mode has been entered, consecutive reads can be performed.
- After power-on, memory read mode is entered.

Table 19-21 AC Characteristics in Memory Read Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

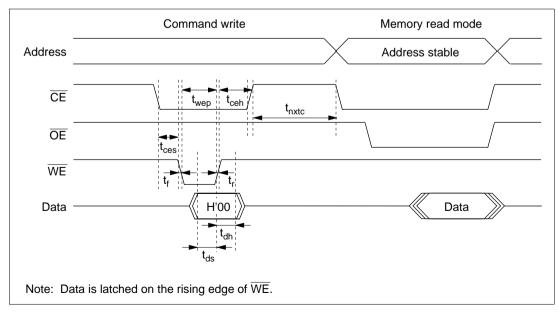


Figure 19-25 Memory Read Mode Timing Waveforms after Command Write

Table 19-22 AC Characteristics when Entering Another Mode from Memory Read Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	\mathbf{t}_{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	$\mathbf{t}_{\sf dh}$	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	\mathbf{t}_{wep}	70	_	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

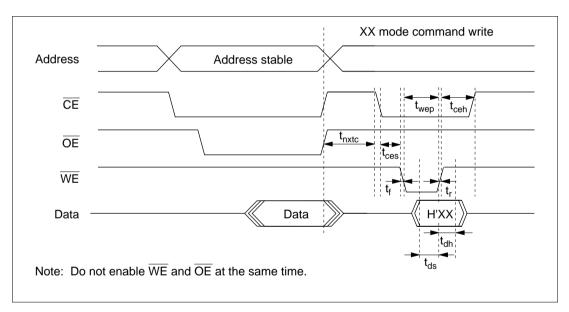


Figure 19-26 Timing Waveforms when Entering Another Mode from Memory Read Mode

Table 19-23 AC Characteristics in Memory Read Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit	
Access time	t _{acc}	_	20	μs	
CE output delay time	t _{ce}	_	150	ns	
OE output delay time	t _{oe}	_	150	ns	
Output disable delay time	t _{df}	_	100	ns	
Data output hold time	t _{oh}	5	_	ns	

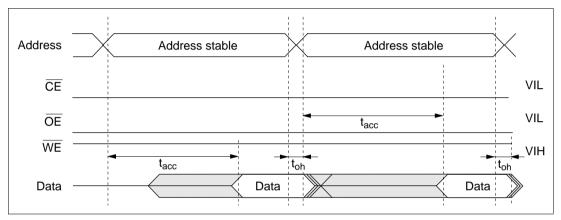


Figure 19-27 Timing Waveforms for CE/OE Enable State Read

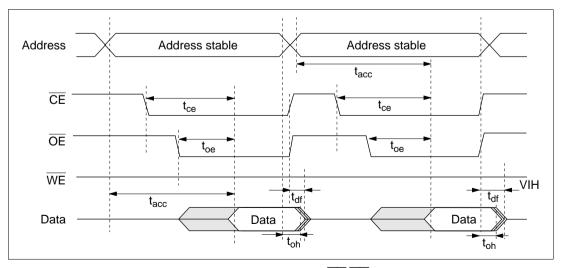


Figure 19-28 Timing Waveforms for $\overline{\text{CE}}/\overline{\text{OE}}$ Clocked Read

19.13.5 Auto-Program Mode

AC Characteristics

Table 19-24 AC Characteristics in Auto-Program Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit
Command write cycle	t _{nxtc}	20	_	μs
CE hold time	t _{ceh}	0	_	ns
CE setup time	t _{ces}	0	_	ns
Data hold time	t _{dh}	50	_	ns
Data setup time	t _{ds}	50	_	ns
Write pulse width	t _{wep}	70	_	ns
Status polling start time	t _{wsts}	1	_	ms
Status polling access time	t _{spa}	_	150	ns
Address setup time	t _{as}	0	_	ns
Address hold time	t _{ah}	60	_	ns
Memory write time	t _{write}	1	3000	ms
WE rise time	t _r	_	30	ns
WE fall time	t _f	_	30	ns
Write setup time	t _{pns}	100	_	ns
Write end setup time	t _{pnh}	100	_	ns

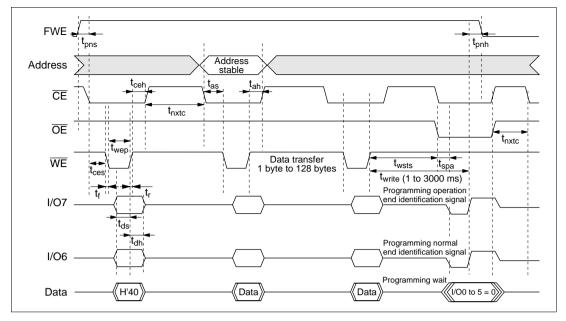


Figure 19-29 Auto-Program Mode Timing Waveforms

Notes on Use of Auto-Program Mode

- In auto-program mode, 128 bytes are programmed simultaneously. This should be carried out by executing 128 consecutive byte transfers.
- A 128-byte data transfer is necessary even when programming fewer than 128 bytes. In this case, H'FF data must be written to the extra addresses.
- The lower 8 bits of the transfer address must be H'00 or H'80. If a value other than an effective
 address is input, processing will switch to a memory write operation but a write error will be
 flagged.
- Memory address transfer is performed in the second cycle (figure 19-29). Do not perform memory address transfer after the second cycle.
- Do not perform a command write during a programming operation.
- Perform one auto-programming operation for a 128-byte block for each address. Characteristics are not guaranteed for two or more programming operations.
- Confirm normal end of auto-programming by checking I/O6. Alternatively, status read mode can also be used for this purpose (I/O7 status polling uses the auto-program operation end identification pin).
- The status polling I/O6 and I/O7 pin information is retained until the next command write. Until the next command write is performed, reading is possible by enabling $\overline{\text{CE}}$ and $\overline{\text{OE}}$.

19.13.6 Auto-Erase Mode

AC Characteristics

Table 19-25 AC Characteristics in Auto-Erase Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit
Command write cycle	t _{nxtc}	20	_	μs
CE hold time	t _{ceh}	0	_	ns
CE setup time	t _{ces}	0	_	ns
Data hold time	t _{dh}	50	_	ns
Data setup time	t _{ds}	50	_	ns
Write pulse width	t _{wep}	70	_	ns
Status polling start time	t _{ests}	1	_	ms
Status polling access time	t_{spa}	_	150	ns
Memory erase time	t _{erase}	100	40000	ms
WE rise time	t _r	_	30	ns
WE fall time	t _f	_	30	ns
Erase setup time	t _{ens}	100	_	ns
Erase end setup time	t _{enh}	100	_	ns

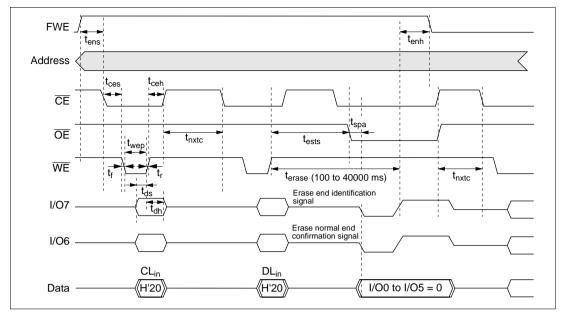


Figure 19-30 Auto-Erase Mode Timing Waveforms

Notes on Use of Auto-Erase Mode

- Auto-erase mode supports only entire memory erasing.
- Do not perform a command write during auto-erasing.
- Confirm normal end of auto-erasing by checking I/O6. Alternatively, status read mode can also be used for this purpose (I/O7 status polling uses the auto-erase operation end identification pin).
- The status polling I/O6 and I/O7 pin information is retained until the next command write. Until the next command write is performed, reading is possible by enabling \overline{CE} and \overline{OE} .

19.13.7 Status Read Mode

- Status read mode is used to identify what type of abnormal end has occurred. Use this mode when an abnormal end occurs in auto-program mode or auto-erase mode.
- The return code is retained until a command write for other than status read mode is performed.

Table 19-26 AC Characteristics in Status Read Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t_{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
OE output delay time	t _{oe}	_	150	ns	
Disable delay time	t_{df}	_	100	ns	
CE output delay time	t _{ce}	_	150	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

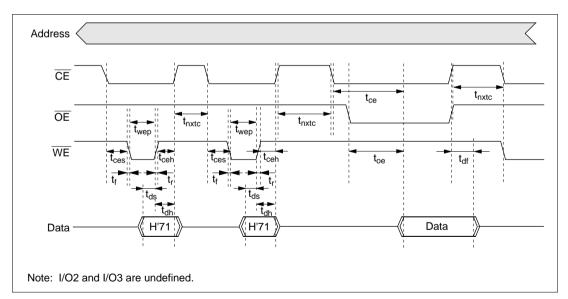


Figure 19-31 Status Read Mode Timing Waveforms

Table 19-27 Status Read Mode Return Commands

Pin Name	1/07	I/O6	I/O5	I/O4	I/O3	I/O2	I/O1	1/00
Attribute	Normal end identification	Command error	Program- ming error	Erase error	_	_	Program- ming or erase count exceeded	Effective address error
Initial value	0	0	0	0	0	0	0	0
Indications	Normal end: 0 Abnormal	Command error: 1 Otherwise: 0	arrar. 1	Erase — — error: 1 Otherwise: 0	_	Count exceeded: 1 Otherwise: 0		
	end: 1	Otherwise. 0					Otherwise. 0	Otherwise: 0

Note: I/O2 and I/O3 are undefined.

19.13.8 Status Polling

- The I/O7 status polling flag indicates the operating status in auto-program or auto-erase mode.
- The I/O6 status polling flag indicates a normal or abnormal end in auto-program or auto-erase mode.

Table 19-28 Status Polling Output Truth Table

Pin Names	Internal Operation in Progress	Abnormal End	_	Normal End
1/07	0	1	0	1
I/O6	0	0	1	1
I/O0 to I/O5	0	0	0	0

19.13.9 Programmer Mode Transition Time

Commands cannot be accepted during the oscillation stabilization period or the programmer mode setup period. After the programmer mode setup time, a transition is made to memory read mode.

Table 19-29 Command Wait State Transition Time Specifications

Item	Symbol	Min	Max	Unit	
Standby release (oscillation stabilization time)	t _{osc1}	10	_	ms	
Programmer mode setup time	t _{bmv}	10	_	ms	
V _{cc} hold time	t _{dwn}	0	_	ms	

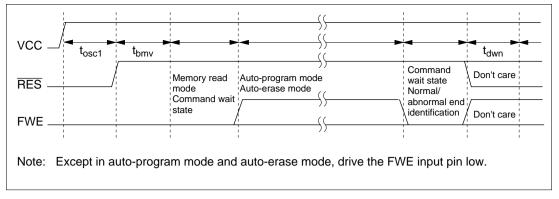


Figure 19-32 Oscillation Stabilization Time, Programmer Mode Setup Time, and Power Supply Fall Sequence

19.13.10 Notes On Memory Programming

- When programming addresses which have previously been programmed, carry out autoerasing before auto-programming.
- When performing programming using writer mode on a chip that has been programmed/erased
 in an on-board programming mode, auto-erasing is recommended before carrying out autoprogramming.
- Notes: 1. The flash memory is initially in the erased state when the device is shipped by Hitachi. For other chips for which the erasure history is unknown, it is recommended that autoerasing be executed to check and supplement the initialization (erase) level.
 - 2. Auto-programming should be performed once only on the same address block.

19.14 Flash Memory Programming and Erasing Precautions

Precautions concerning the use of on-board programming mode, the RAM emulation function, and writer mode are summarized below.

Use the specified voltages and timing for programming and erasing: Applied voltages in excess of the rating can permanently damage the device. Use a PROM programmer that supports Hitachi microcomputer device types with 128-kbyte on-chip flash memory.

Do not select the HN28F101 setting for the PROM programmer, and only use the specified socket adapter. Incorrect use will result in damaging the device.

Powering on and off (see figures 19-33 to 19-35): Do not apply a high level to the FWE pin until V_{CC} has stabilized. Also, drive the FWE pin low before turning off V_{CC} .

When applying or disconnecting V_{CC} , fix the FWE pin low and place the flash memory in the hardware protection state.

The power-on and power-off timing requirements should also be satisfied in the event of a power failure and subsequent recovery.

FWE application/disconnection (see figures 19-33 to 19-35): FWE application should be carried out when MCU operation is in a stable condition. If MCU operation is not stable, fix the FWE pin low and set the protection state.

The following points must be observed concerning FWE application and disconnection to prevent unintentional programming or erasing of flash memory:

- Apply FWE when the V_{CC} voltage has stabilized within its rated voltage range. Apply FWE when oscillation has stabilized (after the elapse of the oscillation settling time).
- In boot mode, apply and disconnect FWE during a reset.
- In user program mode, FWE can be switched between high and low level regardless of the reset state. FWE input can also be switched during program execution in flash memory.
- Do not apply FWE if program runaway has occurred.
- Disconnect FWE only when the SWE, ESU, PSU, EV, PV, P, and E bits in FLMCR1 and FLMCR2 are cleared.
- Make sure that the SWE, ESU, PSU, EV, PV, P, and E bits are not set by mistake when applying or disconnecting FWE.

Do not apply a constant high level to the FWE pin: Apply a high level to the FWE pin only when programming or erasing flash memory. A system configuration in which a high level is constantly applied to the FWE should be avoided. Also, while a high level is applied to the FWE pin, the watchdog timer should be activated to prevent overprogramming or overerasing due to program runaway, etc.

Use the recommended algorithm when programming and erasing flash memory: The recommended algorithm enables programming and erasing to be carried out without subjecting the device to voltage stress or sacrificing program data reliability. When setting the P or E bit in FLMCR1, the watchdog timer should be set beforehand as a precaution against program runaway, etc.

Do not set or clear the SWE bit during program execution in flash memory: Clear the SWE bit before executing a program or reading data in flash memory. When the SWE bit is set, data in flash memory can be rewritten, but flash memory should only be accessed for verify operations (verification during programming/erasing). Similarly, when using the RAM emulation function while a high level is being input to the FWE pin, the SWE bit must be cleared before executing a program or reading data in flash memory. However, the RAM area overlapping flash memory space can be read and written to regardless of whether the SWE bit is set or cleared.

Do not use interrupts while flash memory is being programmed or erased: All interrupt requests, including NMI, should be disabled during FWE application to give priority to program/erase operations.

Do not perform additional programming. Erase the memory before reprogramming. In onboard programming, perform only one programming operation on a 32-byte programming unit block. In writer mode, too, perform only one programming operation on a 128-byte programming unit block. Programming should be carried out with the entire programming unit block erased.

Before programming, check that the chip is correctly mounted in the PROM programmer. Overcurrent damage to the device can result if the index marks on the PROM programmer socket, socket adapter, and chip are not correctly aligned.

Do not touch the socket adapter or chip during programming. Touching either of these can cause contact faults and write errors.

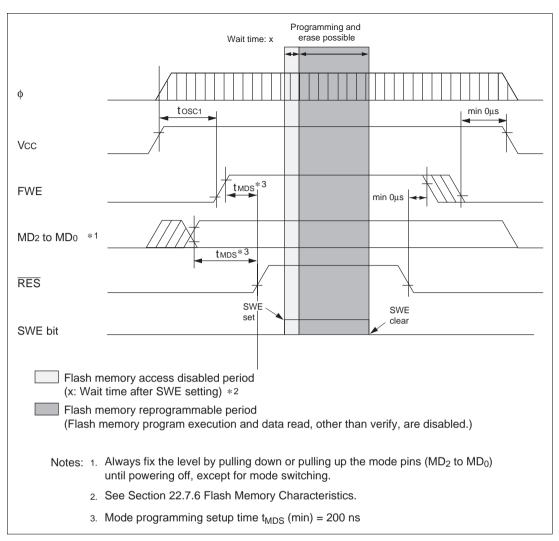


Figure 19-33 Powering On/Off Timing (Boot Mode)

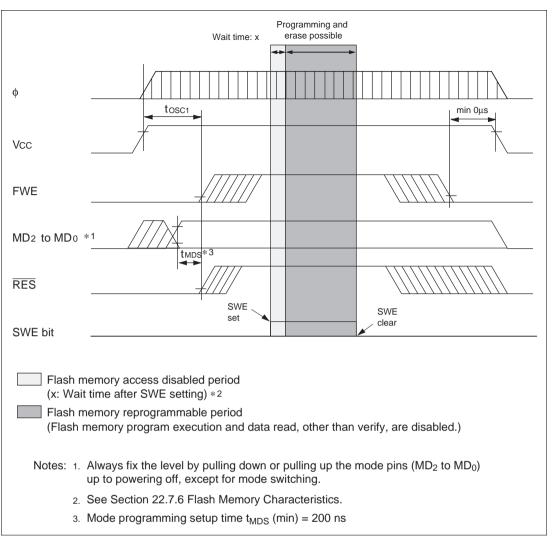


Figure 19-34 Powering On/Off Timing (User Program Mode)

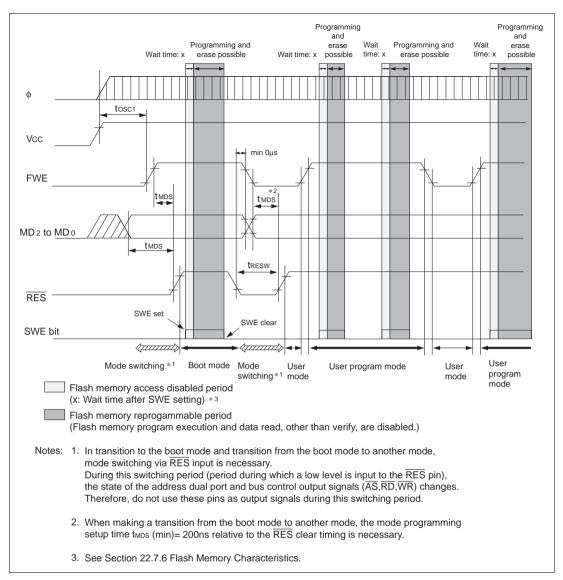


Figure 19-35 Mode Transition Timing (Example: Boot mode \rightarrow User mode \leftrightarrow User program mode)

19.15 Overview of Flash Memory (H8S/2398F-ZTAT)

19.15.1 Features

The H8S/2398F-ZTAT have 256 kbytes of on-chip flash memory. The features of the flash memory are summarized below.

- Four flash memory operating modes
 - Program mode
 - Erase mode
 - Program-verify mode
 - Erase-verify mode

• Programming/erase methods

The flash memory is programmed 128 bytes at a time. Erasing is performed by block erase (in single-block units). To erase the entire flash memory, the individual blocks must be erased sequentially. Block erasing can be performed as required on 4-kbyte, 32-kbyte, and 64-kbyte blocks.

Programming/erase times

The flash memory programming time is TBD ms (typ.) for simultaneous 128-byte programming, equivalent to TBD µs (typ.) per byte, and the erase time is TBD ms (typ.).

· Reprogramming capability

The flash memory can be reprogrammed up to 100 times.

• On-board programming modes

There are two modes in which flash memory can be programmed/erased/verified on-board:

- Boot mode
- User program mode

• Automatic bit rate adjustment

With data transfer in boot mode, the bit rate of the chip can be automatically adjusted to match the transfer bit rate of the host.

• Flash memory emulation by RAM

Part of the RAM area can be overlapped onto flash memory, to emulate flash memory updates in real time.

Protect modes

There are three protect modes, hardware, software, and error protect, which allow protected status to be designated for flash memory program/erase/verify operations.

• Programmer mode

Flash memory can be programmed/erased in programmer mode, using a PROM programmer, as well as in on-board programming mode.

19.15.2 Overview

Block Diagram

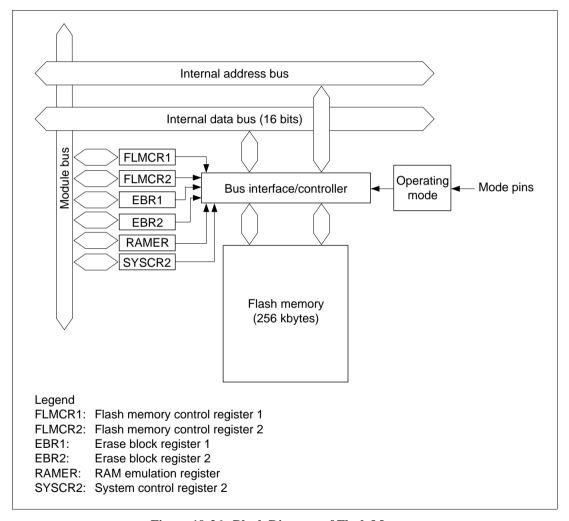


Figure 19-36 Block Diagram of Flash Memory

19.15.3 Flash Memory Operating Modes

Mode Transitions: When the mode pins are set in the reset state and a reset-start is executed, the chip enters one of the operating modes shown in figure 19-37. In user mode, flash memory can be read but not programmed or erased.

Flash memory can be programmed and erased in boot mode, user program mode, and PROM mode.

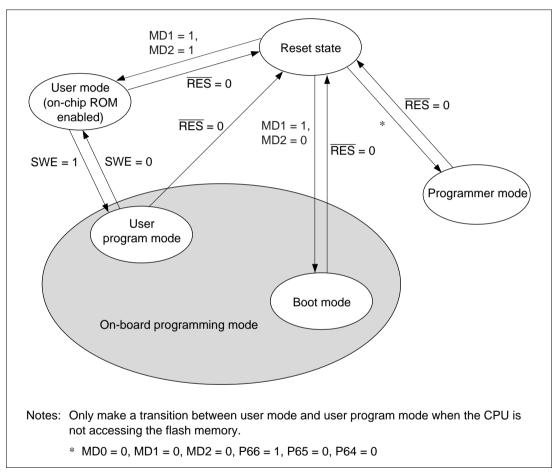


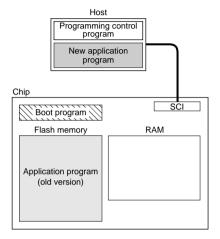
Figure 19-37 Flash Memory Mode Transitions

19.15.4 On-Board Programming Modes

Boot mode

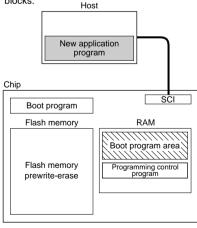
1. Initial state

The old program version or data remains written in the flash memory. The user should prepare the programming control program and new application program beforehand in the host.

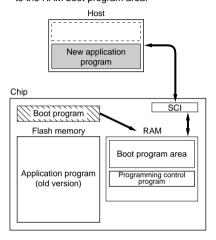


3. Flash memory initialization

The erase program in the boot program area (in RAM) is executed, and the flash memory is initialized (to H'FF). In boot mode, entire flash memory erasure is performed, without regard to blocks.



Programming control program transfer
When boot mode is entered, the boot program in
the chip (originally incorporated in the chip) is
started and the programming control program in
the host is transferred to RAM via SCI
communication. The boot program required for
flash memory erasing is automatically transferred
to the RAM boot program area.



Writing new application program
 The programming control program transferred from the host to RAM is executed, and the new application program in the host is written into the flash memory.

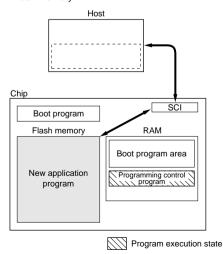
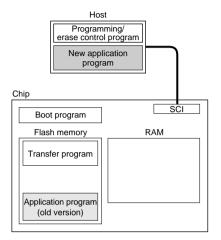


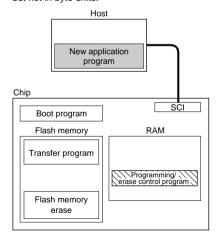
Figure 19-38 Boot Mode

User program mode

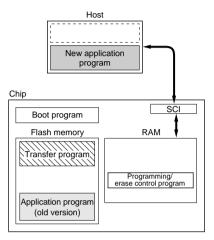
- 1. Initial state
 - (1) The program that will transfer the programming/erase control program to on-chip RAM should be written into the flash memory by the user beforehand. (2) The programming/erase control program should be prepared in the host or in the flash memory.



Flash memory initialization
 The programming/erase program in RAM is executed, and the flash memory is initialized (to H'FF). Erasing can be performed in block units, but not in byte units.



Programming/erase control program transfer Executes the transfer program in the flash memory, and transfers the programming/erase control program to RAM.



Writing new application program
 Next, the new application program in the host is
 written into the erased flash memory blocks. Do
 not write to unerased blocks.

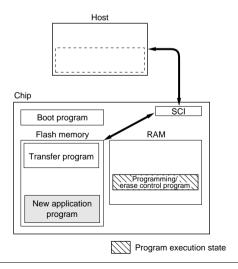


Figure 19-39 User Program Mode (Example)

19.15.5 Flash Memory Emulation in RAM

Reading Overlap RAM Data in User Mode and User Program Mode: Emulation should be performed in user mode or user program mode. When the emulation block set in RAMER is accessed while the emulation function is being executed, data written in the overlap RAM is read.

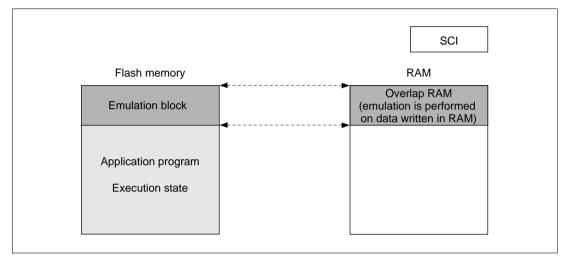


Figure 19-40 Reading Overlap RAM Data in User Mode and User Program Mode

Writing Overlap RAM Data in User Program Mode: When overlap RAM data is confirmed, the RAMS bit is cleared, RAM overlap is released, and writes should actually be performed to the flash memory.

When the programming control program is transferred to RAM, ensure that the transfer destination and the overlap RAM do not overlap, as this will cause data in the overlap RAM to be rewritten.

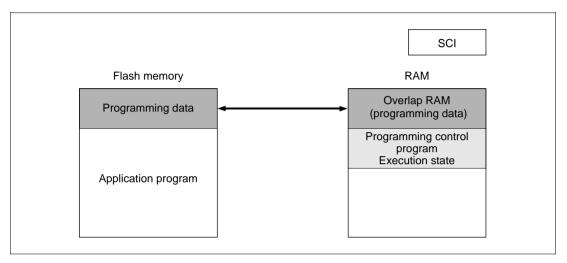


Figure 19-41 Writing Overlap RAM Data in User Program Mode

19.15.6 Differences between Boot Mode and User Program Mode

Table 19-30 Differences between Boot Mode and User Program Mode

	Boot Mode	User Program Mode
Entire memory erase	Yes	Yes
Block erase	No	Yes
Programming control program*	Program/program-verify	Erase/erase-verify/program/ program-verify/emulation

Note: * To be provided by the user, in accordance with the recommended algorithm.

19.15.7 Block Configuration

Products include 256 kbytes of flash memory are divided into three 64-kbyte blocks, one 32-kbyte block, and eight 4-kbyte blocks.

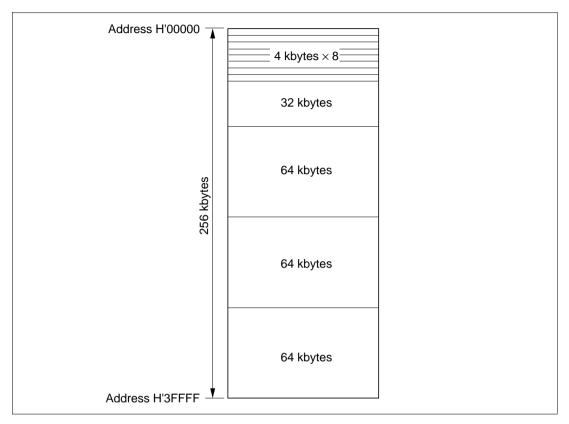


Figure 19-42 Flash Memory Block Configuration

19.15.8 Pin Configuration

The flash memory is controlled by means of the pins shown in table 19-31.

Table 19-31 Flash Memory Pins

Pin Name	Abbreviation	I/O	Function
Reset	RES	Input	Reset
Mode 2	MD2	Input	Sets MCU operating mode
Mode 1	MD1	Input	Sets MCU operating mode
Mode 0	MD0	Input	Sets MCU operating mode
Port 64	P64	Input	Sets MCU operating mode in programmer mode
Port 65	P65	Input	Sets MCU operating mode in programmer mode
Port 66	P66	Input	Sets MCU operating mode in programmer mode
Transmit data	TxD1	Output	Serial transmit data output
Receive data	RxD1	Input	Serial receive data input

19.15.9 Register Configuration

The registers used to control the on-chip flash memory when enabled are shown in table 19-32. In order to access the FLMCR1, FLMCR2, EBR1, and EBR2 registers, the FLSHE bit must be set to 1 in SYSCR2 (except RAMER).

Table 19-32 Flash Memory Registers

Register Name	Abbreviation	R/W	Initial Value	Address*1
Flash memory control register 1	FLMCR1*5	R/W*3	H'80	H'FFC8*2
Flash memory control register 2	FLMCR2*5	R/W*3	H'00*4	H'FFC9*2
Erase block register 1	EBR1*5	R/W*3	H'00*4	H'FFCA*2
Erase block register 2	EBR2*5	R/W*3	H'00*4	H'FFCB*2
System control register 2	SYSCR2*6	R/W	H'00	H'FF42
RAM emulation register	RAMER	R/W	H'00	H'FEDB

Notes: 1. Lower 16 bits of the address.

- 2. Flash memory. Registers selection is performed by the FLSHE bit in system control register 2 (SYSCR2).
- 3. In modes in which the on-chip flash memory is disabled, a read will return H'00, and writes are invalid.
- 4. If a high level is input and the SWE bit in FLMCR1 is not set, these registers are initialized to H'00.
- 5. FLMCR1, FLMCR2, EBR1, and EBR2 are 8-bit registers. Only byte accesses are valid for these registers, the access requiring 2 states.
- 6. The SYSCR2 register can only be used in the F-ZTAT version. In the mask ROM version this register will return an undefined value if read, and cannot be modified.

19.16 Register Descriptions

19.16.1 Flash Memory Control Register 1 (FLMCR1)

Bit	:	7	6	5	4	3	2	1	0
		FWE	SWE	ESU	PSU	EV	PV	Е	Р
Initial value	:	1	0	0	0	0	0	0	0
R/W	:	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W

FLMCR1 is an 8-bit register used for flash memory operating mode control. Program-verify mode or erase-verify mode is entered by setting SWE to 1, then setting the EV or PV bit. Program mode is entered by setting SWE to 1, then setting the PSU bit, and finally setting the P bit. Erase mode is entered by setting SWE to 1, then setting the ESU bit, and finally setting the E bit. FLMCR1 is initialized to H'80 by a reset, and in hardware standby mode and software standby mode. When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

Writing to bits ESU, PSU, EV, and PV in FLMCR1 is enabled only when SWE = 1; writing to the E bit is enabled only when SWE = 1, and ESU = 1; and writing to the P bit is enabled only when SWE = 1, and PSU = 1.

Bit 7—Flash Write Enable Bit (FWE): Sets hardware protection against flash memory programming/erasing. These bits cannot be modified and are always read as 1 in this model.

Bit 6—Software Write Enable Bit (SWE): Enables or disables flash memory programming and erasing. This bit should be set when setting bits 5 to 0, EBR1 bits 7 to 0, and EBR2 bits 3 to 0.

When SWE = 1, the flash memory can only be read in program-verify or erase-verify mode.

Bit 6 SWE	Description	
0	Writes disabled	(Initial value)
1	Writes enabled	

Bit 5—Erase Setup Bit (ESU): Prepares for a transition to erase mode. Do not set the SWE, PSU, EV, PV, E, or P bit at the same time.

ESU	Description	
0	Erase setup cleared	(Initial value)
1	Erase setup	
	[Setting condition]	
	When SWE = 1	

Dit E

Bit 4—Program Setup Bit (PSU): Prepares for a transition to program mode. Do not set the SWE, ESU, EV, PV, E, or P bit at the same time.

Bit 4 PSU	Description	
-30	•	
0	Program setup cleared	(Initial value)
1	Program setup	
	[Setting condition]	
	When SWE = 1	

Bit 3—Erase-Verify (EV): Selects erase-verify mode transition or clearing. Do not set the SWE, ESU, PSU, PV, E, or P bit at the same time.

Bit 3 EV	Description	
0	Erase-verify mode cleared	(Initial value)
1	Transition to erase-verify mode	
	[Setting condition]	
	When SWE = 1	

Bit 2—Program-Verify (PV): Selects program-verify mode transition or clearing. Do not set the SWE, ESU, PSU, EV, E, or P bit at the same time.

Bit 2 PV	Description	
0	Program-verify mode cleared	(Initial value)
1	Transition to program-verify mode	
	[Setting condition]	
	When SWE = 1	

Bit 1—Erase (E): Selects erase mode transition or clearing. Do not set the SWE, ESU, PSU, EV, PV, or P bit at the same time.

Bit 1 E	Description	
0	Erase mode cleared	(Initial value)
1	Transition to erase mode	
	[Setting condition]	
	When SWE = 1, and ESU = 1	

Bit 0—Program (P): Selects program mode transition or clearing. Do not set the SWE, PSU, ESU, EV, PV, or E bit at the same time.

Bit 0 P	Description	
0	Program mode cleared	(Initial value)
1	Transition to program mode	
	[Setting condition]	
	When SWE = 1, and PSU = 1	

19.16.2 Flash Memory Control Register 2 (FLMCR2)

Bit	:	7	6	5	4	3	2	1	0
		FLER	_	_	_	_	_	_	_
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R	_	_	_	_	_	_	_

FLMCR2 is an 8-bit register that controls the flash memory operating modes. FLMCR2 is initialized to H'00 by a reset, and in hardware standby mode and software standby mode.

When on-chip flash memory is disabled, a read will return H'00 and writes are invalid.

Bit 7—Flash Memory Error (FLER): Indicates that an error has occurred during an operation on flash memory (programming or erasing). When FLER is set to 1, flash memory goes to the error-protection state.

Bit 7 FLER	Description	
0	Flash memory is operating normally	(Initial value)
	Flash memory program/erase protection (error protection) is disabled	
	[Clearing condition]	
	Reset or hardware standby mode	
1	An error has occurred during flash memory programming/erasing	
	Flash memory program/erase protection (error protection) is enabled	
	[Setting condition]	
	See section 19.19.3, Error Protection	

Bits 6 to 0—Reserved: These bits cannot be modified and are always read as 0.

19.16.3 Erase Block Register 1 (EBR1)

Bit	:	7	6	5	4	3	2	1	0
EBR1		EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0
Initial val	ue:	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

EBR1 is an 8-bit register that specifies the flash memory erase area block by block. EBR1 is initialized to H'00 by a reset, in hardware standby mode and software standby mode, and the SWE bit in FLMCR1 is not set. When a bit in EBR1 is set, the corresponding block can be erased. Other blocks are erase-protected. Set only one bit in EBR1 and EBR2 together (setting more than one bit will automatically clear all EBR1 and EBR2 bits to 0). When on-chip flash memory is disabled, a read will return H'00 and writes are invalid.

The flash memory block configuration is shown in table 19-33.

19.16.4 Erase Block Registers 2 (EBR2)

Bit :	7	6	5	4	3	2	1	0
EBR2	_	_	_	_	EB11	EB10	EB9	EB8
Initial value:	0	0	0	0	0	0	0	0
R/W :	_	_	_	_	R/W	R/W	R/W	R/W

EBR2 is an 8-bit register that specifies the flash memory erase area block by block. EBR2 is initialized to H'00 by a reset, in hardware standby mode and software standby mode, and the SWE bit in FLMCR1 is not set. When a bit in EBR2 is set, the corresponding block can be erased. Other blocks are erase-protected. Set only one bit in EBR2 and EBR1 together (setting more than one bit will automatically clear all EBR1 and EBR2 bits to 0). Bits 4 to 7 are reserved: they are always read as 0 and cannot be modified. When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

The flash memory block configuration is shown in table 19-33.

Table 19-33 Flash Memory Erase Blocks

Block (Size)	Address
EB0 (4 kbytes)	H'000000 to H'000FFF
EB1 (4 kbytes)	H'001000 to H'001FFF
EB2 (4 kbytes)	H'002000 to H'002FFF
EB3 (4 kbytes)	H'003000 to H'003FFF
EB4 (4 kbytes)	H'004000 to H'004FFF
EB5 (4 kbytes)	H'005000 to H'005FFF
EB6 (4 kbytes)	H'006000 to H'006FFF
EB7 (4 kbytes)	H'007000 to H'007FFF
EB8 (32 kbytes)	H'008000 to H'00FFFF
EB9 (64 kbytes)	H'010000 to H'01FFFF
EB10 (64 kbytes)	H'020000 to H'02FFFF
EB11 (64 kbytes)	H'030000 to H'03FFFF

19.16.5 System Control Register 2 (SYSCR2)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_		FLSHE	_	_	_
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	_	_		_	R/W	_		

SYSCR2 is an 8-bit readable/writable register that performs on-chip flash memory control.

SYSCR2 is initialized to H'00 by a reset and in hardware standby mode.

SYSCR2 can only be used in the F-ZTAT version. In the mask ROM version this register will return an undefined value if read, and cannot be modified.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—Flash Memory Control Register Enable (FLSHE): Controls CPU access to the flash memory control registers (FLMCR1, FLMCR2, EBR1, and EBR2). Writing 1 to the FLSHE bit enables the flash memory control registers to be read and written to. Clearing FLSHE to 0 designates these registers as unselected (the register contents are retained).

Bit 3 FLSHE	Description
0	Flash control registers are not selected for addresses H'FFFC8 to H'FFFCB (Initial value)
1	Flash control registers are selected for addresses H'FFFFC8 to H'FFFFCB

Bits 2 to 0—Reserved: These bits cannot be modified and are always read as 0.

19.16.6 RAM Emulation Register (RAMER)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	RAMS	RAM2	RAM1	RAM0
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	_	_	_	_	R/W	R/W	R/W	R/W

RAMER specifies the area of flash memory to be overlapped with part of RAM when emulating real-time flash memory programming. RAMER is initialized to H'00 by a reset and in hardware standby mode. It is not initialized in software standby mode. RAMER settings should be made in user mode or user program mode.

Flash memory area divisions are shown in table 19-34. To ensure correct operation of the emulation function, the ROM for which RAM emulation is performed should not be accessed immediately after this register has been modified. Normal execution of an access immediately after register modification is not guaranteed.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—RAM Select (RAMS): Specifies selection or non-selection of flash memory emulation in RAM. When RAMS = 1, all flash memory blocks are program/erase-protected.

Bit 3 RAMS	Description	
0	Emulation not selected	(Initial value)
	Program/erase-protection of all flash memory blocks is disabled	
1	Emulation selected	
	Program/erase-protection of all flash memory blocks is enabled	

Bits 2 to 0—Flash Memory Area Selection (RAM2 to RAM0): These bits are used together with bit 3 to select the flash memory area to be overlapped with RAM. (See table 19-34.)

Table 19-34 Flash Memory Area Divisions

RAM Area	Block Name	RAMS	RAM2	RAM1	RAM0
H'FFDC00 to H'FFEBFF	RAM area, 4 kbytes	0	*	*	*
H'000000 to H'000FFF	EB0 (4 kbytes)	1	0	0	0
H'001000 to H'001FFF	EB1 (4 kbytes)	1	0	0	1
H'002000 to H'002FFF	EB2 (4 kbytes)	1	0	1	0
H'003000 to H'003FFF	EB3 (4 kbytes)	1	0	1	1
H'004000 to H'004FFF	EB4 (4 kbytes)	1	1	0	0
H'005000 to H'005FFF	EB5 (4 kbytes)	1	1	0	1
H'006000 to H'006FFF	EB6 (4 kbytes)	1	1	1	0
H'007000 to H'007FFF	EB7 (4 kbytes)	1	1	1	1

*: Don't care

19.17 On-Board Programming Modes

When pins are set to on-board programming mode, program/erase/verify operations can be performed on the on-chip flash memory. There are two on-board programming modes: boot mode and user program mode. The pin settings for transition to each of these modes are shown in table 19-35. For a diagram of the transitions to the various flash memory modes, see figure 19-37.

Table 19-35 Setting On-Board Programming Modes

	Mode	Pins			
MCU Mode	CPU Operating Mode	MD2	MD1	MD0	
Boot mode	Advanced expanded mode with on-chip ROM enabled	0	1	0	
	Advanced single-chip mode	_		1	
User program mode*	Advanced expanded mode with on-chip ROM enabled	1	1	0	
	Advanced single-chip mode	_		1	

Note: *Normally, user mode should be used. Set the SWE bit to 1 to make a transition to user program mode before performing a program/erase/verify operation.

19.17.1 Boot Mode

When boot mode is used, the flash memory programming control program must be prepared in the host beforehand. The channel 1 SCI to be used is set to asynchronous mode.

When a reset-start is executed after the H8S/2398F-ZTAT chip's pins have been set to boot mode, the boot program built into the chip is started and the programming control program prepared in the host is serially transmitted to the chip via the SCI. In the chip, the programming control program received via the SCI is written into the programming control program area in on-chip RAM. After the transfer is completed, control branches to the start address of the programming control program area and the programming control program execution state is entered (flash memory programming is performed).

The transferred programming control program must therefore include coding that follows the programming algorithm given later.

The system configuration in boot mode is shown in figure 19-43, and the boot program mode execution procedure in figure 19-44.

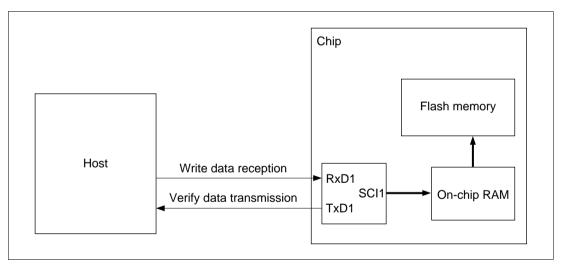


Figure 19-43 System Configuration in Boot Mode

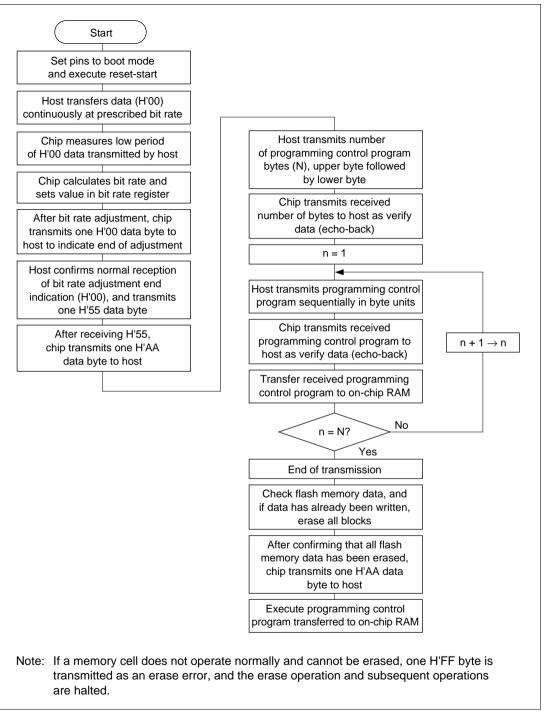


Figure 19-44 Boot Mode Execution Procedure

Automatic SCI Bit Rate Adjustment: When boot mode is initiated, the H8S/2339 or H8S/2329F-ZTAT chip measures the low period of the asynchronous SCI communication data (H'00) transmitted continuously from the host. The SCI transmit/receive format should be set as follows: 8-bit data, 1 stop bit, no parity. The chip calculates the bit rate of the transmission from the host from the measured low period, and transmits one H'00 byte to the host to indicate the end of bit rate adjustment. The host should confirm that this adjustment end indication (H'00) has been received normally, and transmit one H'55 byte to the chip. If reception cannot be performed normally, initiate boot mode again (reset), and repeat the above operations. Depending on the host's transmission bit rate and the chip's system clock frequency, there will be a discrepancy between the bit rates of the host and the chip. To ensure correct SCI operation, the host's transfer bit rate should be set to 9,600 or 19,200 bps.

Table 19-36 shows typical host transfer bit rates and system clock frequencies for which automatic adjustment of the MCU's bit rate is possible. The boot program should be executed within this system clock range.

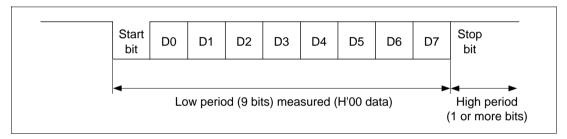
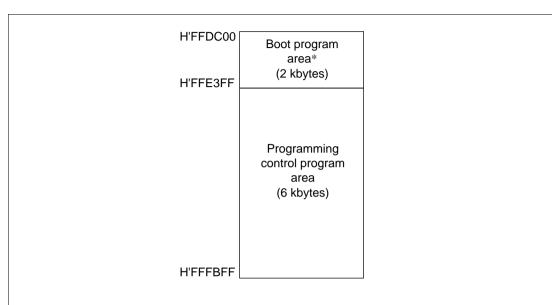


Figure 19-45 Automatic SCI Bit Rate Adjustment

Table 19-36 System Clock Frequencies for which Automatic Adjustment of H8S/2339 or H8S/2329F-ZTAT Bit Rate is Possible

Host Bit Rate	System Clock Frequency for which Automatic Adjustment of H8S/2339 or H8S/2329F-ZTAT Bit Rate is Possible
19,200 bps	10 to 20 MHz
9,600 bps	10 to 20 MHz

On-Chip RAM Area Divisions in Boot Mode: In boot mode, the 2-kbyte area from H'FFDC00 to H'FFE3FF is reserved for use by the boot program, as shown in figure 19-46. The area to which the programming control program is transferred is H'FFE400 to H'FFFBFF. The boot program area can be used when the programming control program transferred into RAM enters the execution state. A stack area should be set up as required.



Note: * The boot program area cannot be used until a transition is made to the execution state for the programming control program transferred to RAM. Note that the boot program remains stored in this area after a branch is made to the programming control program.

Figure 19-46 RAM Areas in Boot Mode

Notes on Use of Boot Mode

- When the chip comes out of reset in boot mode, it measures the low-level period of the input at the SCI's RxD1 pin. The reset should end with RxD1 high. After the reset ends, it takes approximately 100 states before the chip is ready to measure the low-level period of the RxD1 pin.
- In boot mode, if any data has been programmed into the flash memory (if all data is not 1), all flash memory blocks are erased. Boot mode is for use when user program mode is unavailable, such as the first time on-board programming is performed, or if the program activated in user program mode is accidentally erased.
- Interrupts cannot be used while the flash memory is being programmed or erased.
- The RxD1 and TxD1 pins should be pulled up on the board.

- Before branching to the programming control program (RAM area H'FFE400 to H'FFFBFF), the chip terminates transmit and receive operations by the on-chip SCI (channel 1) (by clearing the RE and TE bits in SCR to 0), but the adjusted bit rate value remains set in BRR. The transmit data output pin, TxD1, goes to the high-level output state (P31DDR = 1, P31DR = 1). The contents of the CPU's internal general registers are undefined at this time, so these registers must be initialized immediately after branching to the programming control program. In particular, since the stack pointer (SP) is used implicitly in subroutine calls, etc., a stack area must be specified for use by the programming control program. Initial settings must also be made for the other on-chip registers.
- Boot mode can be entered by making the pin settings shown in table 19-35 and executing a reset-start.
 - Boot mode can be cleared by driving the reset pin low, waiting at least 20 states, then setting the mode pins, and executing reset release*1. Boot mode can also be cleared by a WDT overflow reset.
 - Do not change the mode pin input levels in boot mode.
- If the mode pin input levels are changed (for example, from low to high) during a reset, the state of ports with multiplexed address functions and bus control output pins (AS, RD, HWR) will change according to the change in the microcomputer's operating mode*².

 Therefore, care must be taken to make pin settings to prevent these pins from becoming output
- Notes: 1. Mode pins input must satisfy the mode programming setup time ($t_{MDS} = 200 \text{ ns}$) with respect to the reset release timing.

signal pins during a reset, or to prevent collision with signals outside the microcomputer.

2. See appendix D, Pin States.

19.17.2 User Program Mode

When set to user program mode, the chip can program and erase its flash memory by executing a user program/erase control program. Therefore, on-board reprogramming of the on-chip flash memory can be carried out by providing on-board means supply of programming data, and storing a program/erase control program in part of the program area if necessary.

To select user program mode, select a mode that enables the on-chip flash memory (mode 6 or 7). In this mode, on-chip supporting modules other than flash memory operate as they normally would in modes 6 and 7.

The flash memory itself cannot be read while the SWE bit is set to 1 to perform programming or erasing, so the control program that performs programming and erasing should be run in on-chip RAM or external memory. When the program is located in external memory, an instruction for programming the flash memory and the following instruction should be located in on-chip RAM.

Figure 19-47 shows the procedure for executing the program/erase control program when transferred to on-chip RAM.

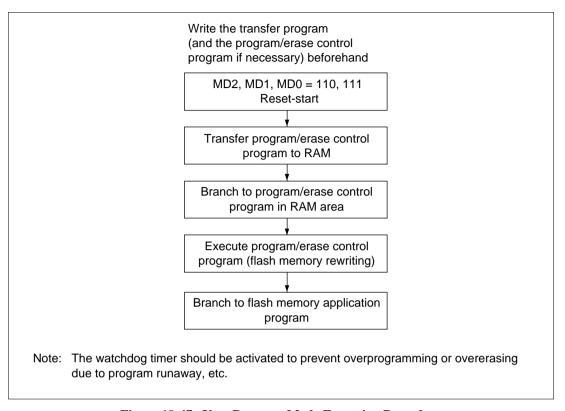


Figure 19-47 User Program Mode Execution Procedure

19.18 Programming/Erasing Flash Memory

In the on-board programming modes, flash memory programming and erasing is performed by software, using the CPU. There are four flash memory operating modes: program mode, erase mode, program-verify mode, and erase-verify mode. Transitions to these modes can be made by setting the PSU, ESU, P, E, PV, and EV bits in FLMCR1.

The flash memory cannot be read while being programmed or erased. Therefore, the program that controls flash memory programming/erasing (the programming control program) should be located and executed in on-chip RAM or external memory. When the program is located in external memory, an instruction for programming the flash memory and the following instruction should be located in on-chip RAM. The DMAC or DTC should not be activated before or after the instruction for programming the flash memory is executed.

- Notes: 1. Operation is not guaranteed if setting/resetting of the SWE, ESU, PSU, EV, PV, E, and P bits in FLMCR1 is executed by a program in flash memory.
 - 2. Perform programming in the erased state. Do not perform additional programming on previously programmed addresses.

19.18.1 Program Mode

Follow the procedure shown in the program/program-verify flowchart in figure 17-14 to write data or programs to flash memory. Performing program operations according to this flowchart will enable data or programs to be written to flash memory without subjecting the device to voltage stress or sacrificing program data reliability. Programming should be carried out 128 bytes at a time.

For the wait times $(x, y, z1, z2, z3 \alpha, \beta, \gamma, \epsilon, \eta, and \theta)$ after bits are set or cleared in flash memory control register 1 (FLMCR1) and the maximum number of programming operations (N), see 22.3.6 the Flash Memory Characteristics section.

Following the elapse of (x) µs or more after the SWE bit is set to 1 in flash memory control register 1 (FLMCR1), 128-byte program data is stored in the program data area and reprogram data area, and the 128-byte data in the reprogram data area is written consecutively to the write addresses. The lower 8 bits of the first address written to must be H'00 or H'80. 128 consecutive byte data transfers are performed. The program address and program data are latched in the flash memory. A 128-byte data transfer must be performed even if writing fewer than 128 bytes; in this case, H'FF data must be written to the extra addresses.

Next, the watchdog timer is set to prevent overprogramming in the event of program runaway, etc. Set a value greater than $(y + z2 + \alpha + \beta)$ µs as the WDT overflow period. After this, preparation for program mode (program setup) is carried out by setting the PSU bit in FLMCR1, and after the elapse of (y) µs or more, the operating mode is switched to program mode by setting the P bit in

FLMCR1. The time during which the P bit is set is the flash memory programming time. Set the programming time according to the table in the programming flowchart.

19.18.2 Program-Verify Mode

In program-verify mode, the data written in program mode is read to check whether it has been correctly written in the flash memory.

After the elapse of a given programming time, the programming mode is exited (the P bit in FLMCR1 is cleared to 0, then the PSU bit is cleared to 0 at least (α) μ later). Next, the watchdog timer is cleared after the elapse of (β) μ s or more, and the operating mode is switched to programverify mode by setting the PV bit in FLMCR1. Before reading in program-verify mode, a dummy write of H'FF data should be made to the addresses to be read. The dummy write should be executed after the elapse of (γ) μ s or more. When the flash memory is read in this state (verify data is read in 16-bit units), the data at the latched address is read. Wait at least (ϵ) μ s after the dummy write before performing this read operation. Next, the originally written data is compared with the verify data, and reprogram data is computed (see figure 19-48) and transferred to the reprogram data area. After 128 bytes of data have been verified, exit program-verify mode in FLMCR1 to 0, and wait again for at least (θ) μ s. If reprogramming is necessary, set program mode again, and repeat the program/program-verify sequence as before. However, ensure that the program/program-verify sequence is not repeated more than (N) times on the same bits.

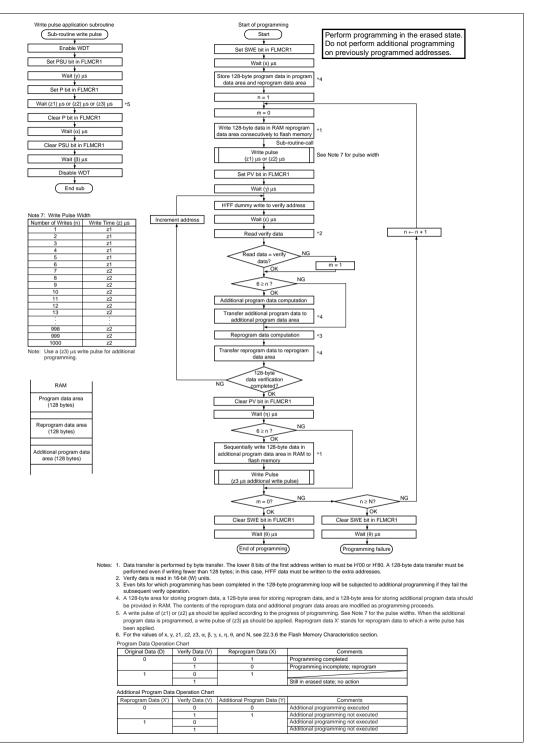


Figure 19-48 Program/Program-Verify Flowchart (Preliminary)

19.18.3 Erase Mode

Flash memory erasing should be performed block by block following the procedure shown in the erase/erase-verify flowchart (single-block erase) shown in figure 19-49.

For the wait times $(x, y, z, \alpha, \beta, \gamma, \varepsilon, \eta, \theta)$ after bits are set or cleared in flash memory control register 1 (FLMCR1) and the maximum number of programming operations (N), see 22.3.6 the Flash Memory Characteristics section.

To perform data or program erasure, make a 1 bit setting for the flash memory area to be erased in erase block register 1 or 2 (EBR1 or EBR2) at least (x) μ s after setting the SWE bit to 1 in flash memory control register 1 (FLMCR1). Next, the watchdog timer is set to prevent overerasing in the event of program runaway, etc. Set a value greater than $(y + z + \alpha + \beta)$ ms as the WDT overflow period. After this, preparation for erase mode (erase setup) is carried out by setting the ESU bit in FLMCR1, and after the elapse of (y) μ s or more, the operating mode is switched to erase mode by setting the E bit in FLMCR1. The time during which the E bit is set is the flash memory erase time. Ensure that the erase time does not exceed (z) ms.

Note: With flash memory erasing, prewriting (setting all data in the memory to be erased to 0) is not necessary before starting the erase procedure.

19.18.4 Erase-Verify Mode

In erase-verify mode, data is read after memory has been erased to check whether it has been correctly erased.

After the elapse of the erase time, erase mode is exited (the E bit in FLMCR1 is cleared to 0, then the ESU bit in FLMCR1 is cleared to 0 at least (α) μ s later), the watchdog timer is cleared after the elapse of (β) μ s or more, and the operating mode is switched to erase-verify mode by setting the EV bit in FLMCR1. Before reading in erase-verify mode, a dummy write of H'FF data should be made to the addresses to be read. The dummy write should be executed after the elapse of (γ) μ s or more. When the flash memory is read in this state (verify data is read in 16-bit units), the data at the latched address is read. Wait at least (ϵ) μ s after the dummy write before performing this read operation. If the read data has been erased (all 1), a dummy write is performed to the next address, and erase-verify is performed. If the read data has not been erased, set erase mode again, and repeat the erase/erase-verify sequence in the same way. However, ensure that the erase/erase-verify sequence is not repeated more than (N) times. When verification is completed, exit erase-verify mode, and wait for at least (η) μ s. If erasure has been completed on all the erase blocks, clear the SWE bit in FLMCR1 to 0 and wait for at least (θ) μ s. If there are any unerased blocks, make a 1 bit setting for the flash memory area to be erased, and repeat the erase/erase-verify sequence in the same way.

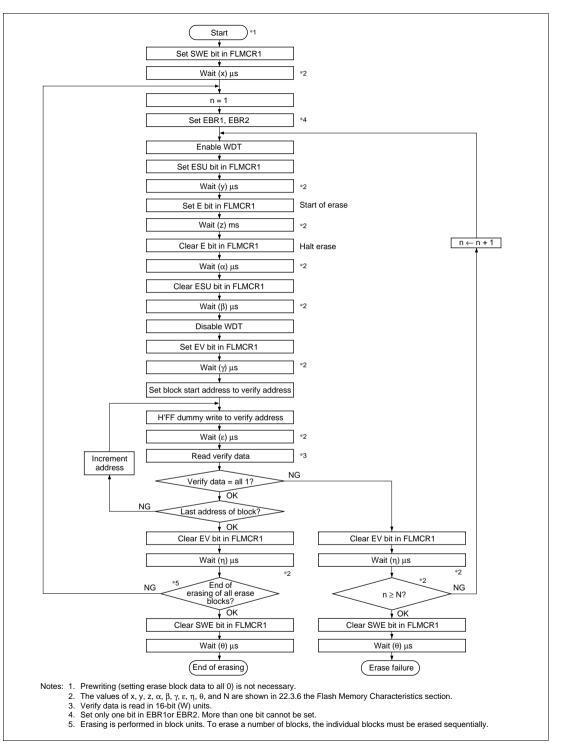


Figure 19-49 Erase/Erase-Verify Flowchart (Preliminary)

19.19 Flash Memory Protection

There are three kinds of flash memory program/erase protection: hardware protection, software protection, and error protection.

19.19.1 Hardware Protection

Hardware protection refers to a state in which programming/erasing of flash memory is forcibly disabled or aborted. Settings in flash memory control registers 1 and 2 (FLMCR1, FLMCR2) and erase block registers 1 and 2 (EBR1, EBR2) are reset. (See table 19-37.)

Table 19-37 Hardware Protection

		Fu	nctions
Item	Description	Program	Erase
Reset/standby protection	 In a reset (including a WDT overflow reset) and in standby mode, FLMCR1, FLMCR2, EBR1, and EBR2 are initialized, and the program/erase-protected state is entered. In a reset via the RES pin, the reset state is not entered unless the RES pin is held low until oscillation stabilizes after powering on. In the case of a reset during operation, hold the RES pin low for the RES pulse width specified in the AC 	Yes	Yes
	Characteristics section.		

19.19.2 Software Protection

Software protection can be implemented by setting the SWE bit in flash memory control register 1 (FLMCR1), erase block registers 1 and 2 (EBR1, EBR2), and the RAMS bit in the RAM emulation register (RAMER). When software protection is in effect, setting the P or E bit in FLMCR1 does not cause a transition to program mode or erase mode. (See table 19-38.)

Table 19-38 Software Protection

			nctions
Item	Description	Program	Erase
SWE bit protection	Clearing the SWE bit to 0 in FLMCR1 sets the program/erase-protected state for all blocks (Execute in on-chip RAM or external memory.)	Yes	Yes
Block specification protection	Erase protection can be set for individual blocks by settings in erase block registers 1 and 2 (EBR1, EBR2).	_	Yes
	• Setting EBR1 and EBR2 to H'00 places all blocks in the erase-protected state.		
Emulation protection	 Setting the RAMS bit to 1 in the RAM emulation register (RAMER) places all blocks in the program/erase-protected state. 	Yes	Yes

19.19.3 Error Protection

In error protection, an error is detected when MCU runaway occurs during flash memory programming/erasing, or operation is not performed in accordance with the program/erase algorithm, and the program/erase operation is aborted. Aborting the program/erase operation prevents damage to the flash memory due to overprogramming or overerasing.

If the MCU malfunctions during flash memory programming/erasing, the FLER bit is set to 1 in FLMCR2 and the error protection state is entered. The FLMCR1, FLMCR2, EBR1, and EBR2 settings are retained, but program mode or erase mode is aborted at the point at which the error occurred. Program mode or erase mode cannot be re-entered by re-setting the P or E bit. However, PV and EV bit setting is enabled, and a transition can be made to verify mode.

FLER bit setting conditions are as follows:

- When flash memory is read during programming/erasing (including a vector read or instruction fetch)
- Immediately after exception handling (excluding a reset) during programming/erasing
- When a SLEEP instruction (including software standby) is executed during programming/erasing
- When the CPU loses the bus during programming/erasing

Error protection is released only by a reset and in hardware standby mode.

Figure 19-50 shows the flash memory state transition diagram.

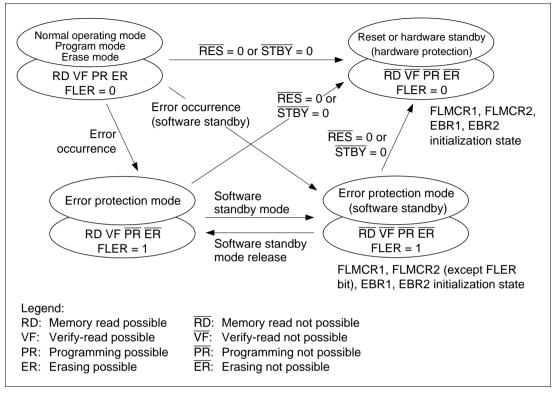


Figure 19-50 Flash Memory State Transitions

19.20 Flash Memory Emulation in RAM

19.20.1 Emulation in RAM

Making a setting in the RAM emulation register (RAMER) enables part of RAM to be overlapped onto the flash memory area so that data to be written to flash memory can be emulated in RAM in real time. After the RAMER setting has been made, accesses can be made from the flash memory area or the RAM area overlapping flash memory. Emulation can be performed in user mode and user program mode. Figure 19-51 shows an example of emulation of real-time flash memory programming.

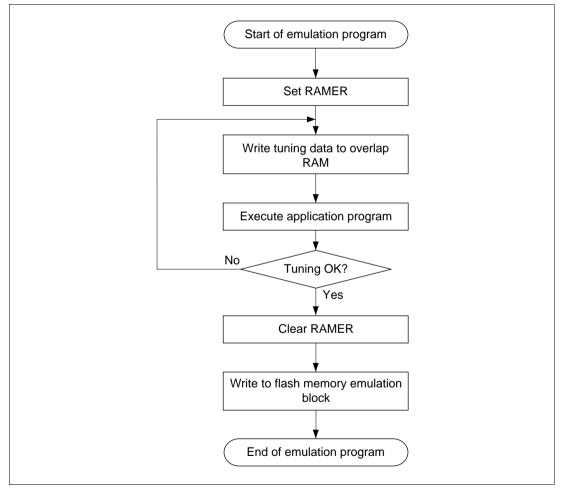


Figure 19-51 Flowchart for Flash Memory Emulation in RAM

19.20.2 RAM Overlap

An example in which flash memory block area EB1 is overlapped is shown below.

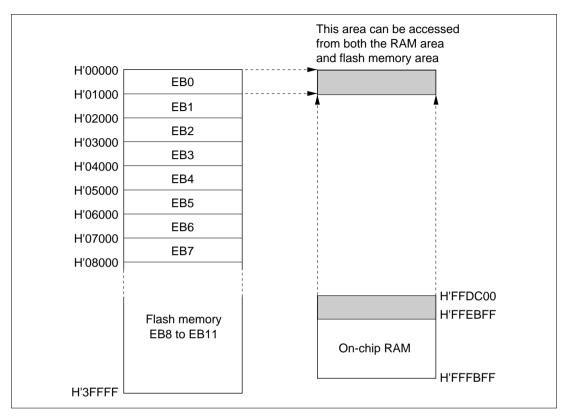


Figure 19-52 Example of RAM Overlap Operation

Example in Which Flash Memory Block Area EB1 is Overlapped

- 1. Set bits RAMS, RAM2, RAM1, and RAM0 in RAMER to 1, 0, 0, 1, to overlap part of RAM onto the area (EB1) for which real-time programming is required.
- 2. Real-time programming is performed using the overlapping RAM.
- 3. After the program data has been confirmed, the RAMS bit is cleared, releasing RAM overlap.
- 4. The data written in the overlapping RAM is written into the flash memory space (EB1).
- Notes: 1. When the RAMS bit is set to 1, program/erase protection is enabled for all blocks regardless of the value of RAM2, RAM1, and RAM0 (emulation protection). In this state, setting the P or E bit in flash memory control register 1 (FLMCR1) will not cause a transition to program mode or erase mode. When actually programming a flash memory area, the RAMS bit should be cleared to 0.

- 2. A RAM area cannot be erased by execution of software in accordance with the erase algorithm while flash memory emulation in RAM is being used.
- 3. Block area EB0 includes the vector table. When performing RAM emulation, the vector table is needed by the overlap RAM.

19.21 Interrupt Handling when Programming/Erasing Flash Memory

All interrupts, including NMI input, are disabled when flash memory is being programmed or erased (when the P or E bit is set in FLMCR1), and while the boot program is executing in boot mode*¹, to give priority to the program or erase operation. There are three reasons for this:

- 1. Interrupt during programming or erasing might cause a violation of the programming or erasing algorithm, with the result that normal operation could not be assured.
- 2. In the interrupt exception handling sequence during programming or erasing, the vector would not be read correctly*2, possibly resulting in MCU runaway.
- 3. If an interrupt occurred during boot program execution, it would not be possible to execute the normal boot mode sequence.

For these reasons, in on-board programming mode alone there are conditions for disabling interrupts, as an exception to the general rule. However, this provision does not guarantee normal erasing and programming or MCU operation. All interrupt requests, including NMI, must therefore be restricted inside and outside the MCU when programming or erasing flash memory. The NMI interrupt is also disabled in the error-protection state while the P or E bit remains set in FLMCR1.

- Notes: 1. Interrupt requests must be disabled inside and outside the MCU until the programming control program has completed programming.
 - 2. The vector may not be read correctly in this case for the following two reasons:
 - If flash memory is read while being programmed or erased (while the P or E bit is set in FLMCR1), correct read data will not be obtained (undetermined values will be returned).
 - If the interrupt entry in the vector table has not been programmed yet, interrupt exception handling will not be executed correctly.

19.22 Flash Memory Programmer Mode

19.22.1 Programmer Mode Setting

Programs and data can be written and erased in programmer mode as well as in the on-board programming modes. In programmer mode, the on-chip ROM can be freely programmed using a PROM programmer that supports the Hitachi microcomputer device type with 256-kbyte on-chip flash memory (FZTAT256V5A). Flash memory read mode, auto-program mode, auto-erase mode, and status read mode are supported with this device type. In auto-program mode, auto-erase mode, and status read mode, a status polling procedure is used, and in status read mode, detailed internal signals are output after execution of an auto-program or auto-erase operation.

Table 19-39 shows programmer mode pin settings.

Table 19-39 Programmer Mode Pin Settings

Pin Names	Settings/External Circuit Connection
Mode pins: MD2, MD1, MD0	Low-level input
Mode setting pins: P66, P65, P64	High-level input to P66, low-level input to P65 and P64
STBY pin	High-level input (do not select hardware standby mode)
RES pin	Reset circuit
XTAL, EXTAL pins	Oscillator circuit
Other pins requiring setting: P32, P25	High-level input to P32, low-level input to P25

19.22.2 Socket Adapters and Memory Map

In programmer mode, a socket adapter is connected to the chip as shown in figures 19-54. Figure 19-53 shows the on-chip ROM memory map and figures 19-54 show the socket adapter pin assignments.

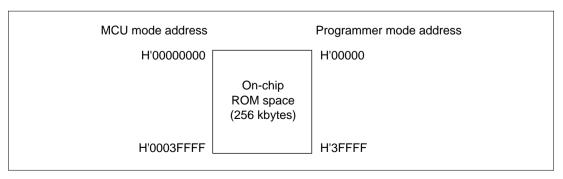


Figure 19-53 Memory Map in Programmer Mode

	H8S/2398F		Socket Adapter	HN27C4096HG (40 Pins)		
TFP-120	FP-128	Pin Name	(40-Pin Conversion)	Pin No.	Pin Name	
2	6	A ₀		21	A ₀	
3	7	A ₁		22	A ₁	
4	8	A ₂		23	A ₂	
5	9	A ₃		24	A ₃	
7	11	A ₄		25	A ₄	
8	12	A ₅		26	A ₅	
9	13	A ₆		27	A ₆	
10	14	A ₇		28	A ₇	
11	15	A ₈		29	A ₈	
12	16	A ₉		31	A ₉	
13	17	A ₁₀		32	A ₁₀	
14	18	A ₁₁		33	A ₁₁	
16	20	A ₁₂		34	A ₁₂	
17	21	A ₁₃	-	35	A ₁₃	
18	22	A ₁₄		36	A ₁₄	
19	23	A ₁₅		37	A ₁₅	
20	24	A ₁₆		38	A ₁₆	
21	25	A ₁₇		39	A ₁₇	
22	26	A ₁₈		10	A ₁₈	
43	49	D ₈		19	I/O ₀	
44	50	D ₉	-	18	I/O ₁	
45	51	D ₁₀		17	I/O ₂	
46	52	D ₁₁		16	I/O ₃	
48	54	D ₁₂		15	I/O ₄	
49	55	D ₁₃		14	I/O ₅	
50	56	D ₁₄		13	I/O ₆	
51	57	D ₁₅		12	I/O ₇	
68	76	CE	-	_ 2	CE	
69	77	ŌĒ		20	ŌĒ	
67	75	WE		3	WE	
72	80	V _{CL} *3	Capacitor	4	FWE	
1, 30, 33, 52, 55,74,	5, 34, 39, 58, 61, 82,			1, 40	V _{CC}	
75, 76, 81, 93, 94	83, 84, 89, 103, 104	V _{cc}		11, 30	V _{SS}	
6, 15, 24, 31, 32, 38,	3, 10, 19, 28, 35, 36,			5, 6, 7	NC	
6, 15, 24, 31, 32, 36, 1 47, 59, 66, 79, 103,	37, 38, 44, 53, 65,			8	A ₂₀	
104, 113, 114, 115	67, 68, 74, 87, 99,	V _{SS}	; ;	9	A ₁₉	
	100, 113, 114, 123, 124, 125			Legend		
73	81	RES	Reset circuit *1	I/O ₇ to I/O ₀ : Da		
77	85	XTAL			dress input	
78	86		Oscillation circuit *2		ip enable tput enable	
	r pins	N.C. (OPEN)			ite enable	

Notes: 1. A reset oscillation stabilization time (t_{osc1}) of at least 10 ms is required.

- 2. A 12 MHz crystal resonator should be used.
- 3. The V_{CL} pin should be connected to V_{SS} by using a capacitor of 0.47 μF (preliminary).

This figure shows pin assignments, and does not show the entire socket adapter circuit.

Figure 19-54 H8S/2329F-ZTAT Socket Adapter Pin Assignments

19.22.3 Programmer Mode Operation

Table 19-40 shows how the different operating modes are set when using programmer mode, and table 19-41 lists the commands used in programmer mode. Details of each mode are given below.

Memory Read Mode: Memory read mode supports byte reads.

Auto-Program Mode: Auto-program mode supports programming of 128 bytes at a time. Status polling is used to confirm the end of auto-programming.

Auto-Erase Mode: Auto-erase mode supports automatic erasing of the entire flash memory. Status polling is used to confirm the end of auto-erasing.

Status Read Mode: Status polling is used for auto-programming and auto-erasing, and normal termination can be confirmed by reading the I/O6 signal. In status read mode, error information is output if an error occurs.

Table 19-40 Settings for Each Operating Mode in Programmer Mode

Pin Names

Mode	CE	ŌĒ	WE	I/O ₇ to I/O ₀	A ₁₈ to A ₀
Read	L	L	Н	Data output	Ain
Output disable	L	Н	Н	Hi-z	Х
Command write	L	Н	L	Data input	Ain* ²
Chip disable*1	Н	Χ	Х	Hi-z	Х

Legend:

H: High level

L: Low level

Hi-z: High impedance

X: Don't care

Notes: 1. Chip disable is not a standby state; internally, it is an operation state.

2. Ain indicates that there is also address input in auto-program mode.

Table 19-41 Programmer Mode Commands

	Number	1st Cycle			2nd Cycle		
Command Name	of Cycles	Mode	Address	Data	Mode	Address	Data
Memory read mode	1 + n	Write	Х	H'00	Read	RA	Dout
Auto-program mode	129	Write	Х	H'40	Write	PA	Din
Auto-erase mode	2	Write	Х	H'20	Write	Х	H'20
Status read mode	2	Write	Х	H'71	Write	Х	H'71

Legend:

RA: Read address

PA: Program address

Notes: 1. In auto-program mode, 129 cycles are required for command writing by a simultaneous 128-byte write.

2. In memory read mode, the number of cycles depends on the number of address write cycles (n).

19.22.4 Memory Read Mode

- After the end of an auto-program, auto-erase, or status read operation, the command wait state
 is entered. To read memory contents, a transition must be made to memory read mode by
 means of a command write before the read is executed.
- Command writes can be performed in memory read mode, just as in the command wait state.
- Once memory read mode has been entered, consecutive reads can be performed.
- After power-on, memory read mode is entered.

Table 19-42 AC Characteristics in Memory Read Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t_dh	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t_{wep}	70	_	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

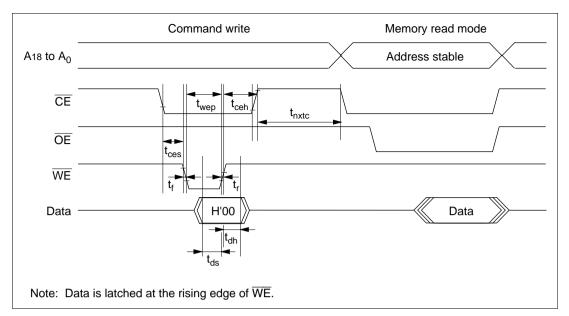


Figure 19-55 Memory Read Mode Timing Waveforms after Command Write

Table 19-43 AC Characteristics when Entering Another Mode from Memory Read Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	_
CE setup time	t _{ces}	0	_	ns	_
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t_{wep}	70	_	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

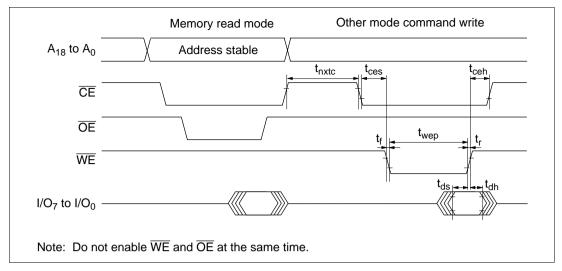


Figure 19-56 Timing Waveforms when Entering Another Mode from Memory Read Mode

Table 19-44 AC Characteristics in Memory Read Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Access time	t _{acc}	_	20	μs	
CE output delay time	t _{ce}	_	150	ns	
OE output delay time	t _{oe}	_	150	ns	
Output disable delay time	t _{df}	_	100	ns	
Data output hold time	t _{oh}	5		ns	_

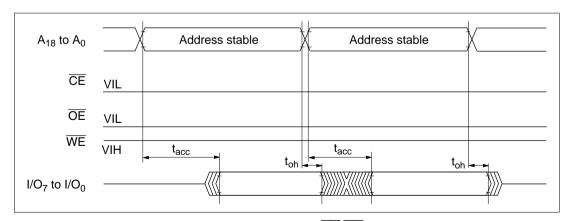


Figure 19-57 Timing Waveforms for $\overline{\text{CE}}/\overline{\text{OE}}$ Enable State Read

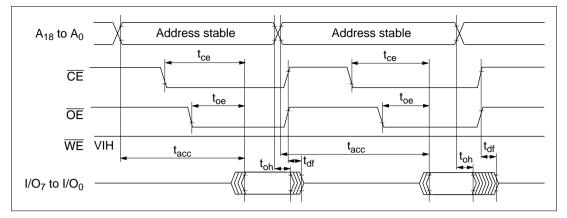


Figure 19-58 Timing Waveforms for $\overline{\text{CE}}/\overline{\text{OE}}$ Clocked Read

19.22.5 Auto-Program Mode

- In auto-program mode, 128 bytes are programmed simultaneously. For this purpose, 128 consecutive byte data transfers should be performed.
- A 128-byte data transfer must be performed even if writing fewer than 128 bytes; in this case, H'FF data must be written to the extra addresses.
- The lower 7 bits of the transfer address must be held low. If an invalid address is input, memory programming will be started but a programming error will occur.
- Memory address transfer is executed in the second cycle (figure 19-59). Do not perform transfer later than the second cycle.
- Do not perform a command write during a programming operation.
- Perform one auto-programming operation for a 128-byte block for each address. One or more
 additional programming operations cannot be carried out on address blocks that have already
 been programmed.
- Confirm normal end of auto-programming by checking I/O₆. Alternatively, status read mode can also be used for this purpose (the I/O₇ status polling pin is used to identify the end of an auto-program operation).
- Status polling I/O₆ and I/O₇ information is retained until the next command write. As long as the next command write has not been performed, reading is possible by enabling $\overline{\text{CE}}$ and $\overline{\text{OE}}$.

AC Characteristics

Table 19-45 AC Characteristics in Auto-Program Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit
Command write cycle	t _{nxtc}	20	_	μs
CE hold time	t _{ceh}	0	_	ns
CE setup time	t _{ces}	0	_	ns
Data hold time	t _{dh}	50	_	ns
Data setup time	t _{ds}	50	_	ns
Write pulse width	t _{wep}	70	_	ns
Status polling start time	t _{wsts}	1	_	ms
Status polling access time	t _{spa}	_	150	ns
Address setup time	t _{as}	0	_	ns
Address hold time	t_{ah}	60	_	ns
Memory write time	t _{write}	1	3000	ms
WE rise time	t _r	_	30	ns
WE fall time	t _f	_	30	ns

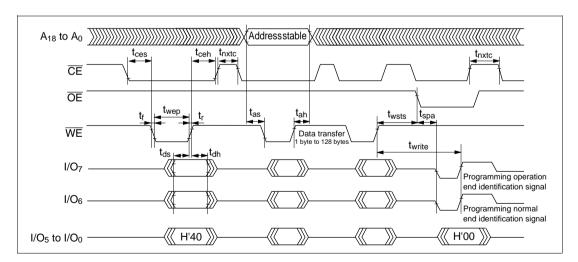


Figure 19-59 Auto-Program Mode Timing Waveforms

19.22.6 Auto-Erase Mode

- Auto-erase mode supports only total memory erasing.
- Do not perform a command write during auto-erasing.
- Confirm normal end of auto-erasing by checking I/O₆. Alternatively, status read mode can also be used for this purpose (the I/O7 status polling pin is used to identify the end of an auto-erase operation).
- Status polling I/O₆ and I/O₇ pin information is retained until the next command write. As long
 as the next command write has not been performed, reading is possible by enabling \(\overline{CE}\) and
 \(\overline{OE}\).

AC Characteristics

Table 19-46 AC Characteristics in Auto-Erase Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t_{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
Status polling start time	t _{ests}	1	_	ms	
Status polling access time	t _{spa}	_	150	ns	
Memory erase time	t _{erase}	100	40000	ms	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

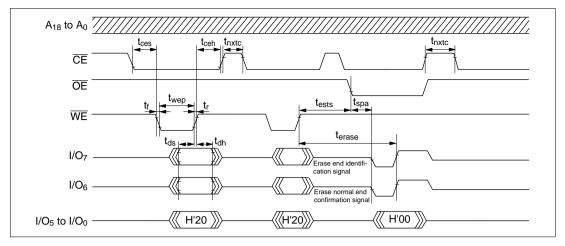


Figure 19-60 Auto-Erase Mode Timing Waveforms

19.22.7 Status Read Mode

- Status read mode is used to identify what type of abnormal end has occurred. Use this mode when an abnormal end occurs in auto-program mode or auto-erase mode.
- The return code is retained until a command write for other than status read mode is performed.

Table 19-47 AC Characteristics in Status Read Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
OE output delay time	t _{oe}	_	150	ns	
Disable delay time	t _{df}	_	100	ns	
CE output delay time	t _{ce}	_	150	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

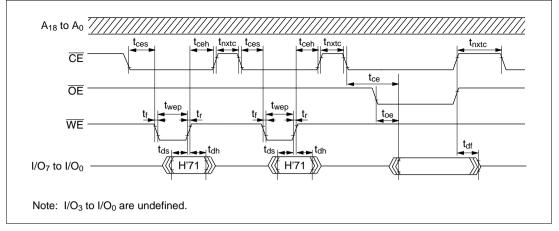


Figure 19-61 Status Read Mode Timing Waveforms

Table 19-48 Status Read Mode Return Commands

Pin Name	I/O ₇	I/O ₆	I/O ₅	I/O ₄	I/O ₃	I/O ₂	I/O ₁	I/O ₀
Attribute	Normal end identification	Command error	Program- ming error	Erase error	_	_	Program- ming or erase count exceeded	Effective address error
Initial value	0	0	0	0	0	0	0	0
Indications	Normal end: 0	Command error: 1	Program- ming	Erase error: 1	_	_	Count exceeded: 1	
	Abnormal end: 1	Otherwise: 0	error: 1 Otherwise: 0	Otherwise: 0			Otherwise: 0	error: 1 Otherwise: 0

Note: I/O₂ and I/O₃ are undefined.

19.22.8 Status Polling

- The I/O_7 status polling flag indicates the operating status in auto-program or auto-erase mode.
- The I/O₆ status polling flag indicates a normal or abnormal end in auto-program or auto-erase mode.

Table 19-49 Status Polling Output Truth Table

Pin Names	Internal Operation in Progress	Abnormal End	_	Normal End
I/O ₇	0	1	0	1
I/O ₆	0	0	1	1
I/O ₀ to I/O ₅	0	0	0	0

19.22.9 Programmer Mode Transition Time

Commands cannot be accepted during the oscillation stabilization period or the programmer mode setup period. After the programmer mode setup time, a transition is made to memory read mode.

Table 19-50 Command Wait State Transition Time Specifications

Item	Symbol	Min	Max	Unit	
Standby release (oscillation stabilization time)	t _{osc1}	30	_	ms	
Programmer mode setup time	$t_{\sf bmv}$	10	_	ms	
V _{cc} hold time	t_{dwn}	0	_	ms	

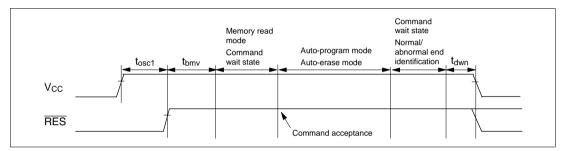


Figure 19-62 Oscillation Stabilization Time, Programmer Mode Setup Time, and Power Supply Fall Sequence

19.22.10 Notes On Memory Programming

- When programming addresses which have previously been programmed, carry out autoerasing before auto-programming.
- When performing programming using writer mode on a chip that has been programmed/erased in an on-board programming mode, auto-erasing is recommended before carrying out autoprogramming.
- Notes: 1. The flash memory is initially in the erased state when the device is shipped by Hitachi. For other chips for which the erasure history is unknown, it is recommended that autoerasing be executed to check and supplement the initialization (erase) level.
 - Auto-programming should be performed once only on the same address block.
 Additional programming cannot be carried out on address blocks that have already been programmed.

19.23 Flash Memory Programming and Erasing Precautions

Precautions concerning the use of on-board programming mode, the RAM emulation function, and programmer mode are summarized below.

Use the specified voltages and timing for programming and erasing: Applied voltages in excess of the rating can permanently damage the device. Use a PROM programmer that supports the Hitachi microcomputer device type with 256-kbyte on-chip flash memory (FZTAT256V5A).

Do not select the HN27C4096 setting for the PROM programmer, and only use the specified socket adapter. Failure to observe these points may result in damage to the device.

Powering on and off: When applying or disconnecting V_{CC} power, fix the \overline{RES} pin low and place the flash memory in the hardware protection state.

The power-on and power-off timing requirements should also be satisfied in the event of a power failure and subsequent recovery.

Use the recommended algorithm when programming and erasing flash memory: The recommended algorithm enables programming and erasing to be carried out without subjecting the device to voltage stress or sacrificing program data reliability. When setting the P or E bit in FLMCR1, the watchdog timer should be set beforehand as a precaution against program runaway, etc.

Do not set or clear the SWE bit during execution of a program in flash memory: Wait for at least 100 μs after clearing the SWE bit before executing a program or reading data in flash memory. When the SWE bit is set, data in flash memory can be rewritten, but when SWE = 1, flash memory can only be read in program-verify or erase-verify mode. Access flash memory only for verify operations (verification during programming/erasing). Also, do not clear the SWE bit during programming, erasing, or verifying.

Similarly, when using the RAM emulation function the SWE bit must be cleared before executing a program or reading data in flash memory.

However, the RAM area overlapping flash memory space can be read and written to regardless of whether the SWE bit is set or cleared.

Do not use interrupts while flash memory is being programmed or erased: When flash memory is programmed or erased, all interrupt requests, including NMI, should be disabled to give priority to program/erase operations.

Do not perform additional programming. Erase the memory before reprogramming: In onboard programming, perform only one programming operation on a 128-byte programming unit block. In programmer mode, too, perform only one programming operation on a 128-byte

programming unit block. Programming should be carried out with the entire programming unit block erased.

Before programming, check that the chip is correctly mounted in the PROM programmer: Overcurrent damage to the device can result if the index marks on the PROM programmer socket, socket adapter, and chip are not correctly aligned.

Do not touch the socket adapter or chip during programming: Touching either of these can cause contact faults and write errors.

19.24 Overview of Flash Memory (H8S/2396, H8S/2395F-ZTAT)

19.24.1 Features

The H8S/2396 and H8S/2395F-ZTAT have 512 or 384 kbytes of on-chip flash memory. The features of the flash memory are summarized below.

- Four flash memory operating modes
 - Program mode
 - Erase mode
 - Program-verify mode
 - Erase-verify mode

• Programming/erase methods

The flash memory is programmed 128 bytes at a time. Erasing is performed by block erase (in single-block units). To erase the entire flash memory, the individual blocks must be erased sequentially. Block erasing can be performed as required on 4-kbyte, 32-kbyte, and 64-kbyte blocks.

• Programming/erase times

The flash memory programming time is TBD ms (typ.) for simultaneous 128-byte programming, equivalent to TBD µs (typ.) per byte, and the erase time is TBD ms (typ.).

· Reprogramming capability

The flash memory can be reprogrammed up to 100 times.

• On-board programming modes

There are two modes in which flash memory can be programmed/erased/verified on-board:

- Boot mode
- User program mode

• Automatic bit rate adjustment

With data transfer in boot mode, the bit rate of the chip can be automatically adjusted to match the transfer bit rate of the host.

• Flash memory emulation by RAM

Part of the RAM area can be overlapped onto flash memory, to emulate flash memory updates in real time.

Protect modes

There are three protect modes, hardware, software, and error protect, which allow protected status to be designated for flash memory program/erase/verify operations.

• Programmer mode

Flash memory can be programmed/erased in programmer mode, using a PROM programmer, as well as in on-board programming mode.

19.24.2 Overview

Block Diagram

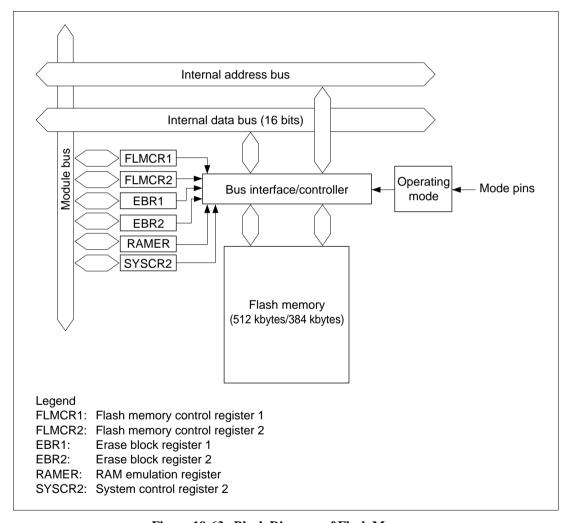


Figure 19-63 Block Diagram of Flash Memory

19.24.3 Flash Memory Operating Modes

Mode Transitions: When the mode pins are set in the reset state and a reset-start is executed, the chip enters one of the operating modes shown in figure 19-64. In user mode, flash memory can be read but not programmed or erased.

Flash memory can be programmed and erased in boot mode, user program mode, and PROM mode.

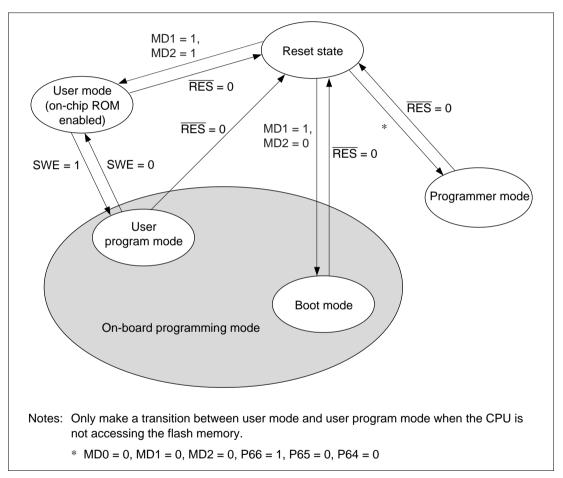


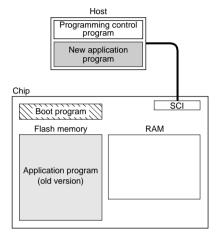
Figure 19-64 Flash Memory Mode Transitions

19.24.4 On-Board Programming Modes

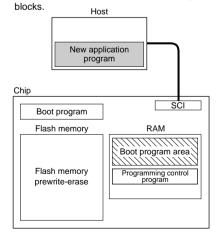
Boot mode

1. Initial state

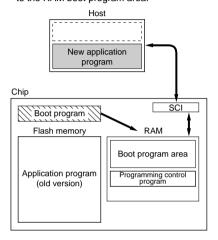
The old program version or data remains written in the flash memory. The user should prepare the programming control program and new application program beforehand in the host.



Flash memory initialization
 The erase program in the boot program area (in RAM) is executed, and the flash memory is initialized (to H'FF). In boot mode, entire flash memory erasure is performed, without regard to



Programming control program transfer
When boot mode is entered, the boot program in
the chip (originally incorporated in the chip) is
started and the programming control program in
the host is transferred to RAM via SCI
communication. The boot program required for
flash memory erasing is automatically transferred
to the RAM boot program area.



Writing new application program
 The programming control program transferred from the host to RAM is executed, and the new application program in the host is written into the flash memory.

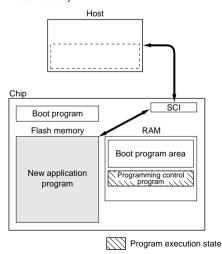
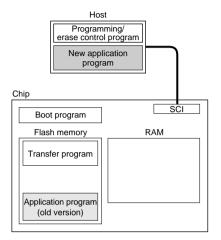


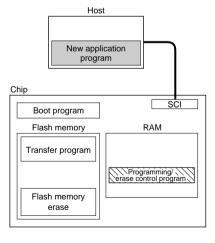
Figure 19-65 Boot Mode

User program mode

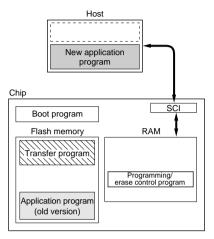
- 1. Initial state
 - (1) The program that will transfer the programming/erase control program to on-chip RAM should be written into the flash memory by the user beforehand. (2) The programming/erase control program should be prepared in the host or in the flash memory.



Flash memory initialization
 The programming/erase program in RAM is executed, and the flash memory is initialized (to H'FF). Erasing can be performed in block units, but not in byte units.



Programming/erase control program transfer Executes the transfer program in the flash memory, and transfers the programming/erase control program to RAM.



Writing new application program
 Next, the new application program in the host is written into the erased flash memory blocks. Do not write to unerased blocks.

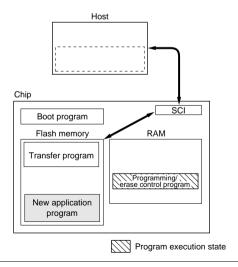


Figure 19-66 User Program Mode (Example)

19.24.5 Flash Memory Emulation in RAM

Reading Overlap RAM Data in User Mode and User Program Mode: Emulation should be performed in user mode or user program mode. When the emulation block set in RAMER is accessed while the emulation function is being executed, data written in the overlap RAM is read.

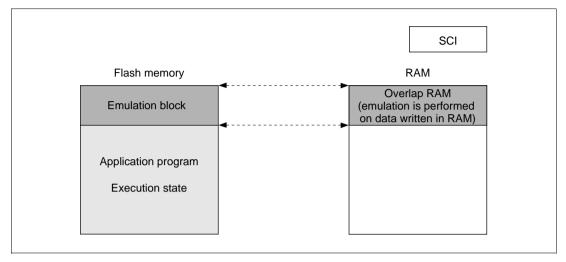


Figure 19-67 Reading Overlap RAM Data in User Mode and User Program Mode

Writing Overlap RAM Data in User Program Mode: When overlap RAM data is confirmed, the RAMS bit is cleared, RAM overlap is released, and writes should actually be performed to the flash memory.

When the programming control program is transferred to RAM, ensure that the transfer destination and the overlap RAM do not overlap, as this will cause data in the overlap RAM to be rewritten.

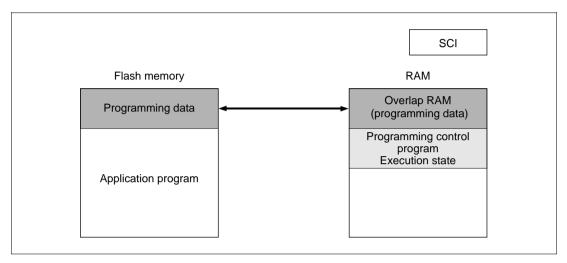


Figure 19-68 Writing Overlap RAM Data in User Program Mode

19.24.6 Differences between Boot Mode and User Program Mode

Table 19-51 Differences between Boot Mode and User Program Mode

	Boot Mode	User Program Mode
Entire memory erase	Yes	Yes
Block erase	No	Yes
Programming control program*	Program/program-verify	Erase/erase-verify/program/ program-verify/emulation

Note: * To be provided by the user, in accordance with the recommended algorithm.

19.24.7 Block Configuration

The H8S/2396 is divided into seven 64-kbyte blocks, one 32-kbyte block, and eight 4-kbyte blocks.

The H8S/2395 is divided into five 64-kbyte blocks, one 32-kbyte block, and eight 4-kbyte blocks.

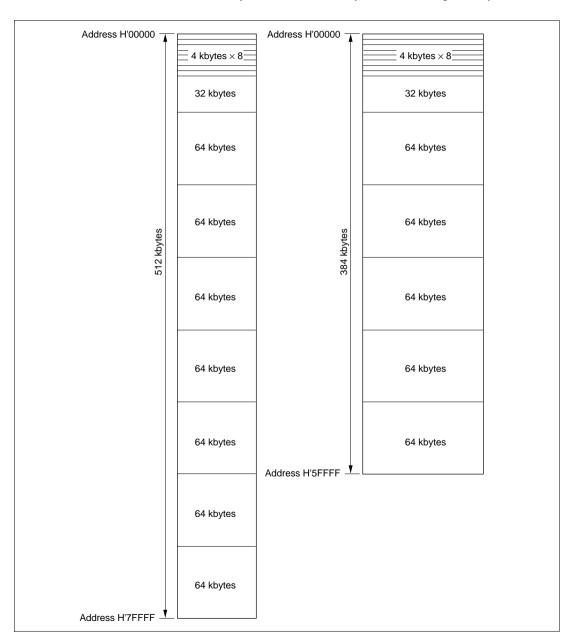


Figure 19-69 Flash Memory Block Configuration

19.24.8 Pin Configuration

The flash memory is controlled by means of the pins shown in table 19-52.

Table 19-52 Flash Memory Pins

Pin Name	Abbreviation	I/O	Function
Reset	RES	Input	Reset
Mode 2	MD2	Input	Sets MCU operating mode
Mode 1	MD1	Input	Sets MCU operating mode
Mode 0	MD0	Input	Sets MCU operating mode
Port 64	P64	Input	Sets MCU operating mode in programmer mode
Port 65	P65	Input	Sets MCU operating mode in programmer mode
Port 66	P66	Input	Sets MCU operating mode in programmer mode
Transmit data	TxD1	Output	Serial transmit data output
Receive data	RxD1	Input	Serial receive data input

19.24.9 Register Configuration

The registers used to control the on-chip flash memory when enabled are shown in table 19-53. In order to access the FLMCR1, FLMCR2, EBR1, and EBR2 registers, the FLSHE bit must be set to 1 in SYSCR2 (except RAMER).

Table 19-53 Flash Memory Registers

Register Name	Abbreviation	R/W	Initial Value	Address*1
Flash memory control register 1	FLMCR1*5	R/W*3	H'80	H'FFC8*2
Flash memory control register 2	FLMCR2*5	R/W*3	H'00* ⁴	H'FFC9*2
Erase block register 1	EBR1* ⁵	R/W*3	H'00*4	H'FFCA*2
Erase block register 2	EBR2* ⁵	R/W*3	H'00*4	H'FFCB*2
System control register 2	SYSCR2*6	R/W	H'00	H'FF42
RAM emulation register	RAMER	R/W	H'00	H'FEDB

Notes: 1. Lower 16 bits of the address.

- 2. Flash memory. Registers selection is performed by the FLSHE bit in system control register 2 (SYSCR2).
- 3. In modes in which the on-chip flash memory is disabled, a read will return H'00, and writes are invalid.
- 4. If a high level is input and the SWE bit in FLMCR1 is not set, these registers are initialized to H'00.
- 5. FLMCR1, FLMCR2, EBR1, and EBR2 are 8-bit registers. Only byte accesses are valid for these registers, the access requiring 2 states.
- 6. The SYSCR2 register can only be used in the F-ZTAT version. In the mask ROM version this register will return an undefined value if read, and cannot be modified.

19.25 Register Descriptions

19.25.1 Flash Memory Control Register 1 (FLMCR1)

Bit	:	7	6	5	4	3	2	1	0
		FWE	SWE1	ESU1	PSU1	EV1	PV1	E1	P1
Initial va	alue :	1	0	0	0	0	0	0	0
R/W	:	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W

FLMCR1 is an 8-bit register used for flash memory operating mode control. Program-verify mode or erase-verify mode for addresses H'000000 to H'03FFFF is entered by setting SWE1 to 1 then setting the EV1 or PV1 bit. Program mode for addresses H'000000 to H'03FFFF is entered by setting SWE1 to 1 then setting the PSU1 bit, and finally setting the P1 bit. Erase mode for addresses H'000000 to H'03FFFF is entered by setting SWE1 to 1 then setting the ESU1 bit, and finally setting the E1 bit. FLMCR1 is initialized to H'80 by a reset, and in hardware standby mode and software standby mode. When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

Writes to bits ESU1, PSU1, EV1, and PV1 only when SWE1 = 1; writes to the E1 bit only when SWE1 = 1, and ESU1 = 1; and writes to the P1 bit only when SWE1 = 1, and PSU1 = 1.

Bit 7—Flash Write Enable Bit (FWE): Sets hardware protection against flash memory programming/erasing. This bit cannot be modified and is always read as 1 in this model.

Bit 6—Software Write Enable Bit 1 (SWE1): Enables or disables flash memory programming and erasing for addresses H'000000 to H'03FFFF. This bit should be set when setting bits 5 to 0, EBR1 bits 7 to 0, and EBR2 bits 3 to 0.

When SWE1 = 1, the flash memory can only be read in program-verify or erase-verify mode.

Bit 6 SWE1	Description	
0	Writes disabled	(Initial value)
1	Writes enabled	

Bit 5—Erase Setup Bit 1 (ESU1): Prepares for a transition to erase mode for addresses H'000000 to H'03FFFF. Do not set the SWE1, PSU1, EV1, PV1, E1, or P1 bit at the same time.

Bit 5 ESU1	Description	
0	Erase setup cleared	(Initial value)
1	Erase setup	
	[Setting condition]	
	When SWE1 = 1	

Bit 4—Program Setup Bit 1 (PSU1): Prepares for a transition to program mode for addresses H'000000 to H'03FFFF. Do not set the SWE1, ESU1, EV1, PV1, E1, or P1 bit at the same time.

Bit 4 PSU1	Description	
0	Program setup cleared	(Initial value)
1	Program setup	
	[Setting condition]	
	When SWE1 = 1	

Bit 3—Erase-Verify 1 (EV1): Selects erase-verify mode transition or clearing for addresses H'000000 to H'03FFFF. Do not set the SWE1, ESU1, PSU1, PV1, E1, or P1 bit at the same time.

Bit 3 EV1	Description	
0	Erase-verify mode cleared	(Initial value)
1	Transition to erase-verify mode	
	[Setting condition]	
	When SWE1 = 1	

Bit 2—Program-Verify 1 (PV1): Selects program-verify mode transition or clearing for addresses H'000000 to H'03FFFF. Do not set the SWE1, ESU1, PSU1, EV1, E1, or P1 bit at the same time.

Bit 2 PV1	Description	
0	Program-verify mode cleared	(Initial value)
1	Transition to program-verify mode	
	[Setting condition]	
	When SWE1 = 1	

Bit 1—Erase 1 (E1): Selects erase mode transition or clearing for addresses H'000000 to H'03FFFF. Do not set the SWE1, ESU1, PSU1, EV1, PV1, or P1 bit at the same time.

Bit 1 E1	Description	
0	Erase mode cleared	(Initial value)
1	Transition to erase mode	
	[Setting condition]	
	When SWE1 = 1, and ESU1 = 1	

Bit 0—Program 1 (P1): Selects program mode transition or clearing for addresses H'000000 to H'03FFFF. Do not set the SWE1, PSU1, ESU1, EV1, PV1, or E1 bit at the same time.

Bit 0 P1	Description	
0	Program mode cleared	(Initial value)
1	Transition to program mode	
	[Setting condition]	
	When SWE1 = 1, and PSU1 = 1	

19.25.2 Flash Memory Control Register 2 (FLMCR2)

Bit	:	7	6	5	4	3	2	1	0
		FLER	SWE2	ESU2	PSU2	EV2	PV2	E2	P2
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W

FLMCR2 is an 8-bit register used for flash memory operating mode control. Program-verify mode or erase-verify mode for addresses H'040000 to H'07FFFF (H'05FFFF)* is entered by setting SWE2 to 1 then setting the EV2 or PV2 bit. Program mode for addresses H'040000 to H'07FFFF (H'05FFFF)* is entered by setting SWE2 to 1 then setting the PSU2 bit, and finally setting the P2 bit. Erase mode for addresses H'040000 to H'07FFFF (H'05FFFF)* is entered by setting SWE2 to 1 then setting the ESU2 bit, and finally setting the E2 bit. FLMCR2 is initialized to H'00 by a reset, and in hardware standby mode and software standby mode. When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

Writes to bits ESU2, PSU2, EV2, and PV2 only when SWE2 = 1; writes to the E2 bit only when SWE2 = 1, and ESU2 = 1; and writes to the P2 bit only when SWE2 = 1, and PSU2 = 1.

Bit 7—Flash Memory Error (FLER): Indicates that an error has occurred during an operation on flash memory (programming or erasing). When FLER is set to 1, flash memory goes to the error-protection state.

Bit 7 FLER	Description	
0	Flash memory is operating normally	(Initial value)
	Flash memory program/erase protection (error protection) is disabled	
	[Clearing condition]	
	Reset or hardware standby mode	
1	An error has occurred during flash memory programming/erasing	
	Flash memory program/erase protection (error protection) is enabled	
	[Setting condition]	
	See section 19.28.3, Error Protection	

Bit 6—Software Write Enable Bit 2 (SWE2): Enables or disables flash memory programming and erasing for addresses H'040000 to H'07FFFF (H'05FFFF)*¹. This bit should be set when setting bits 5 to 0, and EBR2 bits 7 to $4*^2$.

When SWE2 = 1, the flash memory can only be read in program-verify or erase-verify mode.

Notes: 1. Addresses H'040000 to H'05FFFF are in the H8S/2395.

2. EBR2 bits 5 to 4 in the H8S/2395.

Bit 6 SWE2	Description	
0	Writes disabled	(Initial value)
1	Writes enabled	

Bit 5—Erase Setup Bit 2 (ESU2): Prepares for a transition to erase mode for addresses H'040000 to H'07FFFF (H'05FFFF)*. Do not set the SWE2, PSU2, EV2, PV2, E2, or P2 bit at the same time.

Bit 5 ESU2	Description	
0	Erase setup cleared	(Initial value)
1	Erase setup	
	[Setting condition]	
	When SWE2 = 1	

Bit 4—Program Setup Bit 2 (PSU2): Prepares for a transition to program mode for addresses H'040000 to H'07FFFF (H'05FFFF)*. Do not set the SWE2, ESU2, EV2, PV2, E2, or P2 bit at the same time.

Note: *Addresses H'040000 to H'05FFFF are in the H8S/2395.

Bit 4 PSU2	Description	
0	Program setup cleared	(Initial value)
1	Program setup	
	[Setting condition]	
	When SWE2 = 1	

Bit 3—Erase-Verify 2 (EV2): Selects erase-verify mode transition or clearing for addresses H'040000 to H'07FFFF (H'05FFFF)*. Do not set the SWE2, ESU2, PSU2, PV2, E2, or P2 bit at the same time.

Note: *Addresses H'040000 to H'05FFFF are in the H8S/2395.

Bit 3 EV2	Description	
0	Erase-verify mode cleared	(Initial value)
1	Transition to erase-verify mode	
	[Setting condition]	
	When SWE2 = 1	

Bit 2—Program-Verify 2 (PV2): Selects program-verify mode transition or clearing for addresses H'040000 to H'07FFFF (H'05FFFF)*. Do not set the SWE2, ESU2, PSU2, EV2, E2, or P2 bit at the same time.

Bit 2 PV2	Description	
0	Program-verify mode cleared	(Initial value)
1	Transition to program-verify mode	
	[Setting condition]	
	When SWE2 = 1	

Bit 1—Erase 2 (E2): Selects erase mode transition or clearing for addresses H'040000 to H'07FFFF (H'05FFFF)*. Do not set the SWE2, ESU2, PSU2, EV2, PV2, or P2 bit at the same time.

Note: *Addresses H'040000 to H'05FFFF are in the H8S/2395.

Bit 1		
E2	Description	
0	Erase mode cleared	(Initial value)
1	Transition to erase mode	
	[Setting condition]	
	When SWE2 = 1, and ESU2 = 1	

Bit 0—Program 2 (P2): Selects program mode transition or clearing for H'040000 to H'07FFFF (H'05FFFF)*. Do not set the SWE2, PSU2, ESU2, EV2, PV2, or E2 bit at the same time.

Note: *Addresses H'040000 to H'05FFFF are in the H8S/2395.

Bit 0 P2	Description	
0	Program mode cleared	(Initial value)
1	Transition to program mode	
	[Setting condition]	
	When SWE2 = 1, and PSU2 = 1	

19.25.3 Erase Block Register 1 (EBR1)

Bit	:	7	6	5	4	3	2	1	0
EBR1		EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

EBR1 is an 8-bit register that specifies the flash memory erase area block by block. EBR1 is initialized to H'00 by a reset, in hardware standby mode and software standby mode, and the SWE1 bit in FLMCR1 is not set. When a bit in EBR1 is set, the corresponding block can be erased. Other blocks are erase-protected. Set only one bit in EBR1 and EBR2 together (setting more than one bit will automatically clear all EBR1 and EBR2 bits to 0). When on-chip flash memory is disabled, a read will return H'00 and writes are invalid.

The flash memory block configuration is shown in table 19-54.

19.25.4 Erase Block Registers 2 (EBR2)

Bit	:	7	6	5	4	3	2	1	0
EBR2		EB15/(-)*	EB14/(-)*	EB13	EB12	EB11	EB10	EB9	EB8
Initial va	lue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Note: *These bits are reserved in the H8S/2395. Only 0 should be written to these bits.

EBR2 is an 8-bit register that specifies the flash memory erase area block by block. EBR2 is initialized to H'00 by a reset, in hardware standby mode and software standby mode, and when the SWE1 bit in FLMCR1 is not set. When a bit in EBR2 is set, the corresponding block can be erased. Other blocks are erase-protected. Set only one bit in EBR2 and EBR1 together (setting more than one bit will automatically clear all EBR1 and EBR2 bits to 0). When on-chip flash memory is disabled, a read will return H'00, and writes are invalid.

The flash memory block configuration is shown in table 19-54.

Table 19-54 Flash Memory Erase Blocks

Block (Size)	Address
EB0 (4 kbytes)	H'000000 to H'000FFF
EB1 (4 kbytes)	H'001000 to H'001FFF
EB2 (4 kbytes)	H'002000 to H'002FFF
EB3 (4 kbytes)	H'003000 to H'003FFF
EB4 (4 kbytes)	H'004000 to H'004FFF
EB5 (4 kbytes)	H'005000 to H'005FFF
EB6 (4 kbytes)	H'006000 to H'006FFF
EB7 (4 kbytes)	H'007000 to H'007FFF
EB8 (32 kbytes)	H'008000 to H'00FFFF
EB9 (64 kbytes)	H'010000 to H'01FFFF
EB10 (64 kbytes)	H'020000 to H'02FFFF
EB11 (64 kbytes)	H'030000 to H'03FFFF
EB12 (64 kbytes)	H'040000 to H'04FFFF
EB13 (64 kbytes)	H'050000 to H'05FFFF
EB14 (64 kbytes)*	H'060000 to H'06FFFF
EB15 (64 kbytes) *	H'070000 to H'07FFFF

Note: * Valid in the H8S/2396.

19.25.5 System Control Register 2 (SYSCR2)

Bit	:	7	6	5	4	3	2	1	0
		_		_		FLSHE	_	_	_
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	_	_	_	_	R/W	_	_	_

SYSCR2 is an 8-bit readable/writable register that performs on-chip flash memory control.

SYSCR2 is initialized to H'00 by a reset and in hardware standby mode.

SYSCR2 can only be used in the F-ZTAT version. In the mask ROM version this register will return an undefined value if read, and cannot be modified.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—Flash Memory Control Register Enable (FLSHE): Controls CPU access to the flash memory control registers (FLMCR1, FLMCR2, EBR1, and EBR2). Writing 1 to the FLSHE bit enables the flash memory control registers to be read and written to. Clearing FLSHE to 0 designates these registers as unselected (the register contents are retained).

Bit 3
FLSHE Description

O Flash control registers are not selected for addresses H'FFFFC8 to H'FFFFCB (Initial value)

1 Flash control registers are selected for addresses H'FFFFC8 to H'FFFCB

Bits 2 to 0—Reserved: These bits cannot be modified and are always read as 0.

19.25.6 RAM Emulation Register (RAMER)

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	RAMS	RAM2	RAM1	RAM0
Initial valu	ıe:	0	0	0	0	0	0	0	0
R/W	:	_	_	_	_	R/W	R/W	R/W	R/W

RAMER specifies the area of flash memory to be overlapped with part of RAM when emulating real-time flash memory programming. RAMER is initialized to H'00 by a reset and in hardware standby mode. It is not initialized in software standby mode. RAMER settings should be made in user mode or user program mode.

Flash memory area divisions are shown in table 19-55. To ensure correct operation of the emulation function, the ROM for which RAM emulation is performed should not be accessed immediately after this register has been modified. Normal execution of an access immediately after register modification is not guaranteed.

Bits 7 to 4—Reserved: These bits cannot be modified and are always read as 0.

Bit 3—RAM Select (RAMS): Specifies selection or non-selection of flash memory emulation in RAM. When RAMS = 1, all flash memory blocks are program/erase-protected.

Bit 3 RAMS	Description	
0	Emulation not selected	(Initial value)
	Program/erase-protection of all flash memory blocks is disabled	
1	Emulation selected	-
	Program/erase-protection of all flash memory blocks is enabled	

Bits 2 to 0—Flash Memory Area Selection (RAM2 to RAM0): These bits are used together with bit 3 to select the flash memory area to be overlapped with RAM. (See table 19-55.)

Table 19-55 Flash Memory Area Divisions

RAM Area	Block Name	RAMS	RAM2	RAM1	RAM0
H'FFDC00 to H'FFEBFF	RAM area, 4 kbytes	0	*	*	*
H'000000 to H'000FFF	EB0 (4 kbytes)	1	0	0	0
H'001000 to H'001FFF	EB1 (4 kbytes)	1	0	0	1
H'002000 to H'002FFF	EB2 (4 kbytes)	1	0	1	0
H'003000 to H'003FFF	EB3 (4 kbytes)	1	0	1	1
H'004000 to H'004FFF	EB4 (4 kbytes)	1	1	0	0
H'005000 to H'005FFF	EB5 (4 kbytes)	1	1	0	1
H'006000 to H'006FFF	EB6 (4 kbytes)	1	1	1	0
H'007000 to H'007FFF	EB7 (4 kbytes)	1	1	1	1

*: Don't care

19.26 On-Board Programming Modes

When pins are set to on-board programming mode, program/erase/verify operations can be performed on the on-chip flash memory. There are two on-board programming modes: boot mode and user program mode. The pin settings for transition to each of these modes are shown in table 19-56. For a diagram of the transitions to the various flash memory modes, see figure 19-64.

Table 19-56 Setting On-Board Programming Modes

Mode			Pins			
MCU Mode	CPU Operating Mode	MD2	MD1	MD0		
Boot mode	Advanced expanded mode with on-chip ROM enabled	0	1	0		
	Advanced single-chip mode	_		1		
User program mode*	Advanced expanded mode with on-chip ROM enabled	1	1	0		
	Advanced single-chip mode	_		1		

Note: * Normally, user mode should be used. Set the SWE bit to 1 to make a transition to user program mode before performing a program/erase/verify operation.

19.26.1 Boot Mode

When boot mode is used, the flash memory programming control program must be prepared in the host beforehand. The channel 1 SCI to be used is set to asynchronous mode.

When a reset-start is executed after the H8S/2396, H8S/2395F-ZTAT chip's pins have been set to boot mode, the boot program built into the chip is started and the programming control program prepared in the host is serially transmitted to the chip via the SCI. In the chip, the programming control program received via the SCI is written into the programming control program area in on-chip RAM. After the transfer is completed, control branches to the start address of the programming control program area and the programming control program execution state is entered (flash memory programming is performed).

The transferred programming control program must therefore include coding that follows the programming algorithm given later.

The system configuration in boot mode is shown in figure 19-70, and the boot program mode execution procedure in figure 19-71.

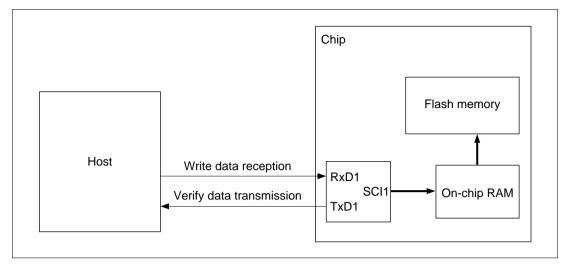


Figure 19-70 System Configuration in Boot Mode

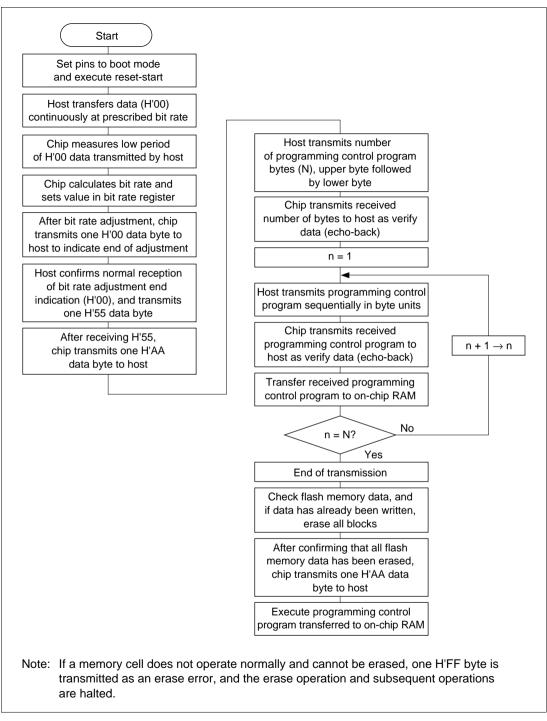


Figure 19-71 Boot Mode Execution Procedure

Automatic SCI Bit Rate Adjustment: When boot mode is initiated, the H8S/2396, H8S/2395F-ZTAT chip measures the low period of the asynchronous SCI communication data (H'00) transmitted continuously from the host. The SCI transmit/receive format should be set as follows: 8-bit data, 1 stop bit, no parity. The chip calculates the bit rate of the transmission from the host from the measured low period, and transmits one H'00 byte to the host to indicate the end of bit rate adjustment. The host should confirm that this adjustment end indication (H'00) has been received normally, and transmit one H'55 byte to the chip. If reception cannot be performed normally, initiate boot mode again (reset), and repeat the above operations. Depending on the host's transmission bit rate and the chip's system clock frequency, there will be a discrepancy between the bit rates of the host and the chip. To ensure correct SCI operation, the host's transfer bit rate should be set to 9,600 or 19,200 bps.

Table 19-57 shows typical host transfer bit rates and system clock frequencies for which automatic adjustment of the MCU's bit rate is possible. The boot program should be executed within this system clock range.

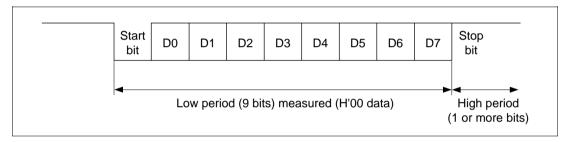
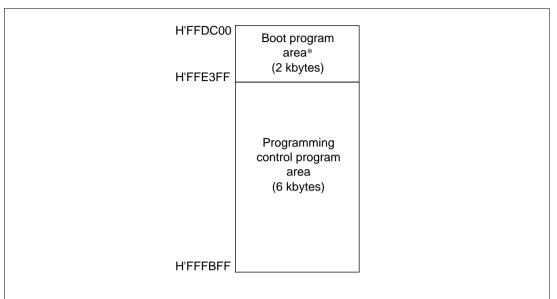


Figure 19-72 Automatic SCI Bit Rate Adjustment

Table 19-57 System Clock Frequencies for which Automatic Adjustment of H8S/2319F-ZTAT Bit Rate is Possible

Host Bit Rate	System Clock Frequency for which Automatic Adjustment of H8S/2319F-ZTAT Bit Rate is Possible
19,200 bps	10 to 20 MHz
9,600 bps	10 to 20 MHz

On-Chip RAM Area Divisions in Boot Mode: In boot mode, the 2-kbyte area from H'FFDC00 to H'FFE3FF is reserved for use by the boot program, as shown in figure 19-73. The area to which the programming control program is transferred is H'FFE400 to H'FFFBFF. The boot program area can be used when the programming control program transferred into RAM enters the execution state. A stack area should be set up as required.



Note: * The boot program area cannot be used until a transition is made to the execution state for the programming control program transferred to RAM. Note that the boot program remains stored in this area after a branch is made to the programming control program.

Figure 19-73 RAM Areas in Boot Mode

Notes on Use of Boot Mode

- When the chip comes out of reset in boot mode, it measures the low-level period of the input at
 the SCI's RxD1 pin. The reset should end with RxD1 high. After the reset ends, it takes
 approximately 100 states before the chip is ready to measure the low-level period of the RxD1
 pin.
- In boot mode, if any data has been programmed into the flash memory (if all data is not 1), all flash memory blocks are erased. Boot mode is for use when user program mode is unavailable, such as the first time on-board programming is performed, or if the program activated in user program mode is accidentally erased.
- Interrupts cannot be used while the flash memory is being programmed or erased.
- The RxD1 and TxD1 pins should be pulled up on the board.

- Before branching to the programming control program (RAM area H'FFE400 to H'FFFBFF), the chip terminates transmit and receive operations by the on-chip SCI (channel 1) (by clearing the RE and TE bits in SCR to 0), but the adjusted bit rate value remains set in BRR. The transmit data output pin, TxD1, goes to the high-level output state (P31DDR = 1, P31DR = 1). The contents of the CPU's internal general registers are undefined at this time, so these registers must be initialized immediately after branching to the programming control program. In particular, since the stack pointer (SP) is used implicitly in subroutine calls, etc., a stack area must be specified for use by the programming control program.
- Boot mode can be entered by making the pin settings shown in table 19-56 and executing a
 reset-start.
 - Boot mode can be cleared by driving the reset pin low, waiting at least 20 states, then setting the mode pins, and executing reset release*1. Boot mode can also be cleared by a WDT overflow reset.
 - Do not change the mode pin input levels in boot mode.

Initial settings must also be made for the other on-chip registers.

- If the mode pin input levels are changed (for example, from low to high) during a reset, the state of ports with multiplexed address functions and bus control output pins (AS, RD, HWR) will change according to the change in the microcomputer's operating mode*2.

 Therefore, care must be taken to make pin settings to prevent these pins from becoming output signal pins during a reset, or to prevent collision with signals outside the microcomputer.
- Notes: 1. Mode pins input must satisfy the mode programming setup time ($t_{MDS} = 200 \text{ ns}$) with respect to the reset release timing.
 - 2. See appendix D, Pin States.

19.26.2 User Program Mode

When set to user program mode, the chip can program and erase its flash memory by executing a user program/erase control program. Therefore, on-board reprogramming of the on-chip flash memory can be carried out by providing an on-board means to supply programming data, and storing a program/erase control program in part of the program area if necessary.

To select user program mode, select a mode that enables the on-chip flash memory (mode 6 or 7). In this mode, on-chip supporting modules other than flash memory operate as they normally would in modes 6 and 7.

While the SWE1 bit is set to 1 to perform programming or erasing for the addresses H'000000 to H'03FFFF, this address area cannot be read. While the SWE2 bit is set to 1 to perform programming or erasing for the addresses H'040000 to H'07FFFF (H'05FFFF)*, this address area cannot be read. The control program that performs programming and erasing should be run in on-chip RAM or flash memory except for the above address areas. When the program is located in

external memory, an instruction for programming the flash memory and the following instruction should be located in on-chip RAM.

Figure 19-74 shows the procedure for executing the program/erase control program when transferred to on-chip RAM.

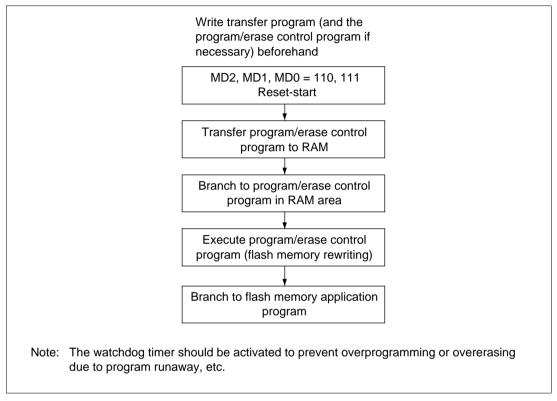


Figure 19-74 User Program Mode Execution Procedure

19.27 Programming/Erasing Flash Memory

In the on-board programming modes, flash memory programming and erasing is performed by software, using the CPU. There are four flash memory operating modes: program mode, erase mode, program-verify mode, and erase-verify mode. Transition to these modes can be made for addresses H'000000 to H'03FFFF by setting the PSU1, ESU1, P1, E1, PV1, and EV1 bits in FLMCR1, and for addresses H'040000 to H'07FFFF (H'05FFFF) by setting the PSU2, ESU2, P2, E2, PV2, and EV2 bits in FLMCR2.

The flash memory cannot be read while being programmed or erased. Therefore, the program that controls flash memory programming/erasing (the programming control program) should be located and executed in on-chip RAM, external memory, or flash memory except for the above address areas. When the program is located in external memory, an instruction for programming the flash memory and the following instruction should be located in on-chip RAM. The DTC should not be activated before or after the instruction for programming the flash memory is executed.

- Notes: 1. Operation is not guaranteed if setting/resetting of the SWE1, ESU1, PSU1, EV1, PV1, E1, and P1 bits in FLMCR1 or setting/resetting of the SWE2, ESU2, PSU2, EV2, PV2, E2, and P2 bits in FLMCR2 is executed by a program in flash memory.
 - 2. Perform programming in the erased state. Do not perform additional programming on previously programmed addresses.
 - 3. Do not program addresses H'000000 to H'03FFFF and H'040000 to H'07FFFF (H'05FFFF) simultaneously. Operation is not guaranteed when programming is performed simultaneously.
 - 4. Target addresses for FLMCR2 become H'040000 to H'05FFFF in the H8S/2395.

19.27.1 Program Mode (n = 1 for addresses H'000000 to H'03FFFF and n = 2 for addresses H'040000 to H'07FFFF (H'05FFFF)*)

Follow the procedure shown in the program/program-verify flowchart in figure 19-75 to write data or programs to flash memory. Performing program operations according to this flowchart will enable data or programs to be written to flash memory without subjecting the device to voltage stress or sacrificing program data reliability. Programming should be carried out 128 bytes at a time.

For the wait times $(x, y, z1, z2, z3 \alpha, \beta, \gamma, \epsilon, \eta, and \theta)$ after bits are set or cleared in flash memory control register n (FLMCRn) and the maximum number of programming operations (N), see 22.3.6 the Flash Memory Characteristics section.

Following the elapse of (x) µs or more after the SWEn bit is set to 1 in flash memory control register n (FLMCRn), 128-byte program data is stored in the program data area and reprogram data area, and the 128-byte data in the reprogram data area is written consecutively to the write addresses. The lower 8 bits of the first address written to must be H'00 or H'80. 128 consecutive 826

byte data transfers are performed. The program address and program data are latched in the flash memory. A 128-byte data transfer must be performed even if writing fewer than 128 bytes; in this case, H'FF data must be written to the extra addresses.

Next, the watchdog timer is set to prevent overprogramming in the event of program runaway, etc. Set a value greater than $(y+z2+\alpha+\beta)$ μ s as the WDT overflow period. After this, preparation for program mode (program setup) is carried out by setting the PSUn bit in FLMCRn, and after the elapse of (y) μ s or more, the operating mode is switched to program mode by setting the Pn bit in FLMCRn. The time during which the Pn bit is set is the flash memory programming time. Set the programming time according to the table in the programming flowchart.

Note: *Addresses H'040000 to H'05FFFF are in the H8S/2395.

19.27.2 Program-Verify Mode (n = 1 for addresses H'000000 to H'03FFFF and n = 2 for addresses H'040000 to H'07FFFF (H'05FFFF)*)

In program-verify mode, the data written in program mode is read to check whether it has been correctly written in the flash memory.

After the elapse of a given programming time, the programming mode is exited (the Pn bit in FLMCRn is cleared to 0, then the PSUn bit is cleared to 0 at least (α) μ s later). Next, the watchdog timer is cleared after the elapse of (β) μ s or more, and the operating mode is switched to program-verify mode by setting the PVn bit in FLMCRn. Before reading in program-verify mode, a dummy write of H'FF data should be made to the addresses to be read. The dummy write should be executed after the elapse of (γ) μ s or more. When the flash memory is read in this state (verify data is read in 16-bit units), the data at the latched address is read. Wait at least (ϵ) μ s after the dummy write before performing this read operation. Next, the originally written data is compared with the verify data, and reprogram data is computed (see figure 19-75) and transferred to the reprogram data area. After 128 bytes of data have been verified, exit program-verify mode and wait for at least (η) μ s, then clear the SWEn bit in FLMCRn to 0, and wait again for at least (θ) μ s. If reprogramming is necessary, set program mode again, and repeat the program/program-verify sequence as before. However, ensure that the program/program-verify sequence is not repeated more than (N) times on the same bits.

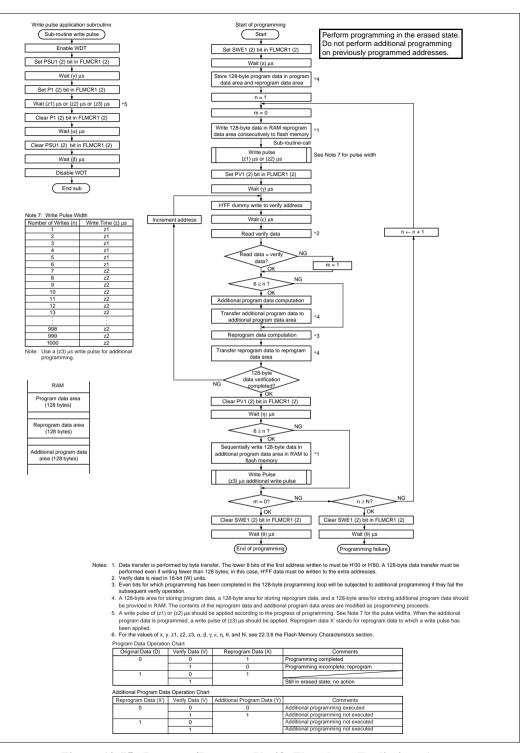


Figure 19-75 Program/Program-Verify Flowchart (Preliminary)

19.27.3 Erase Mode (n = 1 for addresses H'000000 to H'03FFFF and n = 2 for addresses H'040000 to H'07FFFF (H'05FFFF)*)

Flash memory erasing should be performed block by block following the procedure shown in the erase/erase-verify flowchart (single-block erase) shown in figure 19-76.

For the wait times $(x, y, z, \alpha, \beta, \gamma, \epsilon, \eta, \theta)$ after bits are set or cleared in flash memory control register n (FLMCRn) and the maximum number of programming operations (N), see 22.3.6 the Flash Memory Characteristics section.

To perform data or program erasure, make a 1 bit setting for the flash memory area to be erased in erase block register 1 or 2 (EBR1 or EBR2) at least (x) μ s after setting the SWEn bit to 1 in flash memory control register n (FLMCRn). Next, the watchdog timer is set to prevent overerasing in the event of program runaway, etc. Set a value greater than $(y + z + \alpha + \beta)$ ms as the WDT overflow period. After this, preparation for erase mode (erase setup) is carried out by setting the ESUn bit in FLMCRn, and after the elapse of (y) μ s or more, the operating mode is switched to erase mode by setting the En bit in FLMCRn. The time during which the En bit is set is the flash memory erase time. Ensure that the erase time does not exceed (z) ms.

Note: With flash memory erasing, prewriting (setting all data in the memory to be erased to 0) is not necessary before starting the erase procedure.

*Addresses H'040000 to H'05FFFF are in the H8S/2395.

19.27.4 Erase-Verify Mode (n = 1 for addresses H'000000 to H'03FFFF and n = 2 for addresses H'040000 to H'07FFFF (H'05FFFF)*)

In erase-verify mode, data is read after memory has been erased to check whether it has been correctly erased.

After the elapse of the erase time, erase mode is exited (the En bit in FLMCRn is cleared to 0, then the ESUn bit in FLMCRn is cleared to 0 at least (α) μ s later), the watchdog timer is cleared after the elapse of (β) μ s or more, and the operating mode is switched to erase-verify mode by setting the EVn bit in FLMCRn. Before reading in erase-verify mode, a dummy write of H'FF data should be made to the addresses to be read. The dummy write should be executed after the elapse of (γ) μ s or more. When the flash memory is read in this state (verify data is read in 16-bit units), the data at the latched address is read. Wait at least (ϵ) μ s after the dummy write before performing this read operation. If the read data has been erased (all 1), a dummy write is performed to the next address, and erase-verify is performed. If the read data has not been erased, set erase mode again, and repeat the erase/erase-verify sequence in the same way. However, ensure that the erase/erase-verify sequence is not repeated more than (N) times. When verification is completed, exit erase-verify mode, and wait for at least (η) μ s. If erasure has been completed on all the erase blocks, clear the SWEn bit in FLMCRn to 0 and wait for at least (θ) μ s. If there are any unerased blocks,

make a 1 bit setting for the flash memory area to be erased, and repeat the erase/erase-verify sequence in the same way.

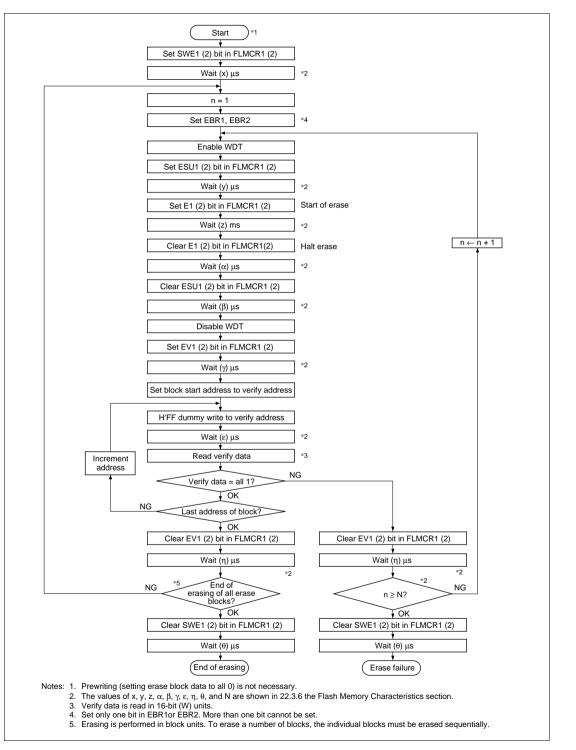


Figure 19-76 Erase/Erase-Verify Flowchart (Preliminary)

19.28 Flash Memory Protection

There are three kinds of flash memory program/erase protection: hardware protection, software protection, and error protection.

19.28.1 Hardware Protection

Hardware protection refers to a state in which programming/erasing of flash memory is forcibly disabled or aborted. Settings in flash memory control registers 1 and 2 (FLMCR1, FLMCR2) and erase block registers 1 and 2 (EBR1, EBR2) are reset. (See table 19-58.)

Table 19-58 Hardware Protection

		Fu	nctions
Item	Description	Program	Erase
Reset/standby protection	 In a reset (including a WDT overflow reset) and in standby mode, FLMCR1, FLMCR2, EBR1, and EBR2 are initialized, and the program/erase-protected state is entered. In a reset via the RES pin, the reset state is not entered unless the RES pin is held low until oscillation stabilizes after powering on. In the case of a reset during operation, hold the RES pin low for the RES pulse width specified in the AC 	Yes	Yes
	Characteristics section.		

19.28.2 Software Protection

Software protection can be implemented by setting the SWE1 bit in flash memory control register 1 (FLMCR1), SWE2 bit in FLMCR2 erase block registers 1 and 2 (EBR1, EBR2), and the RAMS bit in the RAM emulation register (RAMER). When software protection is in effect, setting the P1 or E1 bit in FLMCR1, or the P2 or E2 bit in FLMCR2 does not cause a transition to program mode or erase mode. (See table 19-59.)

Table 19-59 Software Protection

		Functions		
Item	Description	Program	Erase	
SWE bit protection	Clearing the SWE1 bit to 0 in FLMCR1 sets the program/erase-protected state for area H'000000 to H'03FFFF (Execute in on-chip RAM, external memory, or addresses H'040000 to H'07FFFF (H'05FFFF)) Clearing the SWE2 bit to 0 in FLMCR2 sets	Yes	Yes	
	 Clearing the SWE2 bit to 0 in FLMCR2 sets the program/erase-protected state for area H'040000 to H'07FFFF (H'05FFFF) (Execute in on-chip RAM, external memory, or addresses H'0000000 to H'03FFFF) 	3		
Block specification protection	 Erase protection can be set for individual blocks by settings in erase block registers 1 and 2 (EBR1, EBR2). Setting EBR1 and EBR2 to H'00 places all blocks in the erase-protected state. 	_	Yes	
Emulation protection	Setting the RAMS bit to 1 in the RAM emulation register (RAMER) places all blocks in the program/erase-protected state.	Yes	Yes	

Note: *Addresses H'040000 to H'05FFFF are in the H8S/2395.

19.28.3 Error Protection

In error protection, an error is detected when MCU runaway occurs during flash memory programming/erasing, or operation is not performed in accordance with the program/erase algorithm, and the program/erase operation is aborted. Aborting the program/erase operation prevents damage to the flash memory due to overprogramming or overerasing.

If the MCU malfunctions during flash memory programming/erasing, the FLER bit is set to 1 in FLMCR2 and the error protection state is entered. The FLMCR1, FLMCR2, EBR1, and EBR2 settings are retained, but program mode or erase mode is aborted at the point at which the error occurred. Program mode or erase mode cannot be re-entered by re-setting the P1, P2, E1, or E2 bit. However, PV1, PV2, EV1, and EV2 bit setting is enabled, and a transition can be made to verify mode.

FLER bit setting conditions are as follows:

- When flash memory is read during programming/erasing (including a vector read or instruction fetch)
- Immediately after exception handling (excluding a reset) during programming/erasing
- When a SLEEP instruction (including software standby) is executed during programming/erasing
- When the CPU loses the bus during programming/erasing

Error protection is released only by a reset and in hardware standby mode.

Figure 19-77 shows the flash memory state transition diagram.

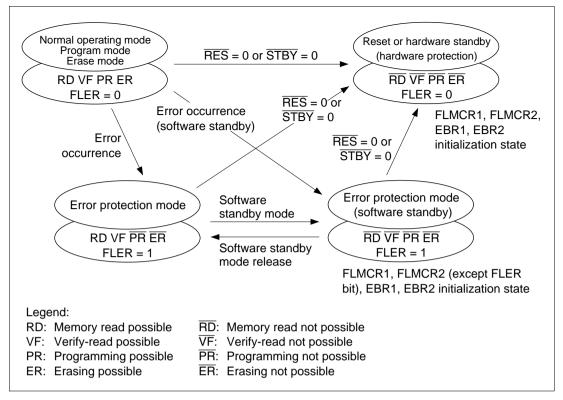


Figure 19-77 Flash Memory State Transitions

19.29 Flash Memory Emulation in RAM

19.29.1 Emulation in RAM

Making a setting in the RAM emulation register (RAMER) enables part of RAM to be overlapped onto the flash memory area so that data to be written to flash memory can be emulated in RAM in real time. After the RAMER setting has been made, accesses can be made from the flash memory area or the RAM area overlapping flash memory. Emulation can be performed in user mode and user program mode. Figure 19-78 shows an example of emulation of real-time flash memory programming.

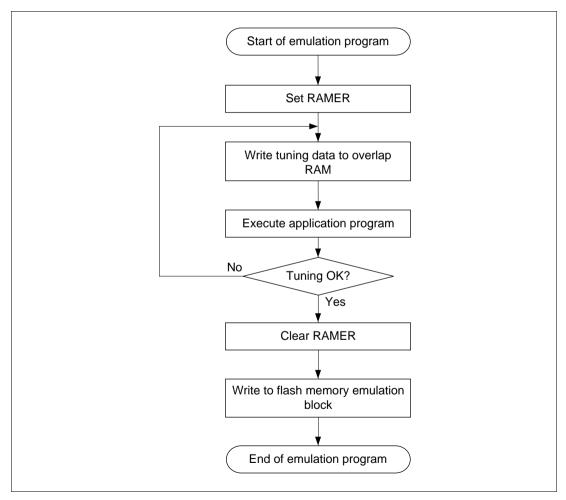


Figure 19-78 Flowchart for Flash Memory Emulation in RAM

19.29.2 **RAM Overlap**

An example in which flash memory block area EB1 is overlapped is shown below.

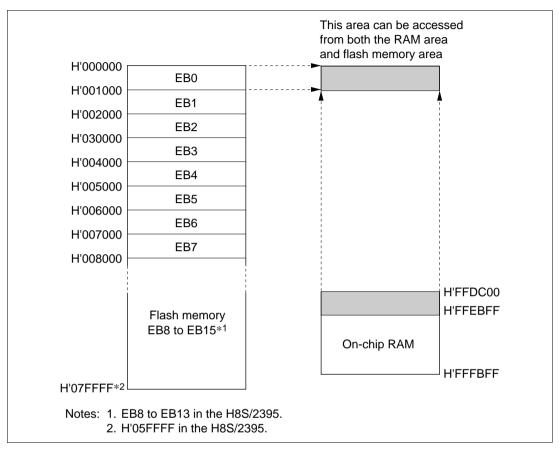


Figure 19-79 Example of RAM Overlap Operation

Example in Which Flash Memory Block Area EB1 is Overlapped

- 1. Set bits RAMS, RAM2, RAM1, and RAM0 in RAMER to 1, 0, 0, 1, to overlap part of RAM onto the area (EB1) for which real-time programming is required.
- 2. Real-time programming is performed using the overlapping RAM.
- 3. After the program data has been confirmed, the RAMS bit is cleared, releasing RAM overlap.
- 4. The data written in the overlapping RAM is written into the flash memory space (EB1).
- Notes: 1. When the RAMS bit is set to 1, program/erase protection is enabled for all blocks regardless of the value of RAM2, RAM1, and RAM0 (emulation protection). In this state, setting the P1 or E1 bit in flash memory control register 1 (FLMCR1), or setting the P2 or E2 bit in FLMCR2 will not cause a transition to program mode or erase

- mode. When actually programming a flash memory area, the RAMS bit should be cleared to 0.
- 2. A RAM area cannot be erased by execution of software in accordance with the erase algorithm while flash memory emulation in RAM is being used.
- 3. Block area EB0 includes the vector table. When performing RAM emulation, the vector table is needed by the overlap RAM.

19.30 Interrupt Handling when Programming/Erasing Flash Memory

All interrupts, including NMI input, are disabled when flash memory is being programmed or erased (when the P1 or E1 bit is set in FLMCR1, or the P2 or E2 bit is set in FLMCR2), and while the boot program is executing in boot mode*1, to give priority to the program or erase operation. There are three reasons for this:

- 1. Interrupt during programming or erasing might cause a violation of the programming or erasing algorithm, with the result that normal operation could not be assured.
- 2. In the interrupt exception handling sequence during programming or erasing, the vector would not be read correctly*², possibly resulting in MCU runaway.
- 3. If an interrupt occurred during boot program execution, it would not be possible to execute the normal boot mode sequence.

For these reasons, in on-board programming mode alone there are conditions for disabling interrupts, as an exception to the general rule. However, this provision does not guarantee normal erasing and programming or MCU operation. All requests, including NMI, must therefore be restricted inside and outside the MCU when programming or erasing flash memory. The NMI interrupt is also disabled in the error-protection state while the P1 or E1 bit remains set in FLMCR1, or the P2 or E2 bit remains set in FLMCR2.

- Notes: 1. Interrupt requests must be disabled inside and outside the MCU until the programming control program has completed programming.
 - 2. The vector may not be read correctly in this case for the following two reasons:
 - If flash memory is read while being programmed or erased (while the P1 or E1 bit is set in FLMCR1, or the P2 or E2 bit is set in FLMCR2.), correct read data will not be obtained (undetermined values will be returned).
 - If the interrupt entry in the vector table has not been programmed yet, interrupt exception handling will not be executed correctly.

19.31 Flash Memory Programmer Mode

19.31.1 Programmer Mode Setting

Programs and data can be written and erased in programmer mode as well as in the on-board programming modes. In programmer mode, the on-chip ROM can be freely programmed using a PROM programmer that supports the Hitachi microcomputer device type with 512-kbyte on-chip flash memory (F-ZTAT512V5A). Flash memory read mode, auto-program mode, auto-erase mode, and status read mode are supported with this device type. In auto-program mode, auto-erase mode, and status read mode, a status polling procedure is used, and in status read mode, detailed internal signals are output after execution of an auto-program or auto-erase operation.

Table 19-60 shows programmer mode pin settings.

Table 19-60 Programmer Mode Pin Settings

Pin Names	Settings/External Circuit Connection
Mode pins: MD2, MD1, MD0	Low-level input
Mode setting pins: P66, P65, P64	High-level input to P66, low-level input to P65 and P64
STBY pin	High-level input (do not select hardware standby mode)
RES pin	Reset circuit
XTAL, EXTAL pins	Oscillator circuit
Other pins requiring setting: P32, P25	High-level input to P32, low-level input to P25

19.31.2 Socket Adapters and Memory Map

In programmer mode, a socket adapter is connected to the chip as shown in figures 19-81. Figure 19-80 shows the on-chip ROM memory map and figures 19-81 shows the socket adapter pin assignments.

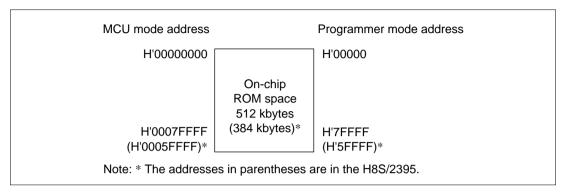


Figure 19-80 Memory Map in Programmer Mode

H8S/2396F, H8S/2395F			Socket Adapter	HN27C4096HG (40 Pins)		
TFP-120	FP-128	Pin Name	(40-Pin Conversion)	Pin No.	Pin Name	
2	6	A ₀		21	A ₀	
3	7	A ₁		22	A ₁	
4	8	A ₂		23	A ₂	
5	9	A ₃		24	A ₃	
7	11	A ₄		25	A ₄	
8	12	A ₅		26	A ₅	
9	13	A ₆		27	A ₆	
10	14	A ₇		28	A ₇	
11	15	A ₈		29	A ₈	
12	16	A ₉		31	A ₉	
13	17	A ₁₀		32	A ₁₀	
14	18	A ₁₁		33	A ₁₁	
16	20	A ₁₂		34	A ₁₂	
17	21	A ₁₃		35	A ₁₃	
18	22	A ₁₄	-	36	A ₁₄	
19	23	A ₁₅		37	A ₁₅	
20	24	A ₁₆		38	A ₁₆	
21	25	A ₁₇		39	A ₁₇	
22	26	A ₁₈		10	A ₁₈	
43	49	D ₈		19	I/O ₀	
44	50	D ₉		18	I/O ₁	
45	51	D ₁₀		17	I/O ₂	
46	52	D ₁₁		16	I/O ₃	
48	54	D ₁₂		15	I/O ₄	
49	55	D ₁₃		14	I/O ₅	
50	56	D ₁₃		13	I/O ₆	
51	57	D ₁₅		12	I/O ₇	
68	76	CE		2	CE	
69	77	ŌĒ		20	ŌĒ	
67	75	WE		3	WE	
72	80	V _{CL} *3	Capacitor	4	FWE	
1, 30, 33, 52, 55,74,	5, 34, 39, 58, 61, 82,	V CL	Capacitor	1, 40	V _{CC}	
75, 76, 81, 93, 94	83, 84, 89, 103, 104	V _{CC}		11, 30	V _{SS}	
				5, 6, 7	NC	
6, 15, 24, 31, 32, 38, 47, 59, 66, 79, 103,	3, 10, 19, 28, 35, 36, 37, 38, 44, 53, 65,			8	A ₂₀	
47, 59, 66, 79, 103, 104, 113, 114, 115	67, 68, 74, 87, 99,	V _{SS}		9	A ₁₉	
, -, , ,	100, 113, 114, 123,			Legend	1 ,,18	
	124, 125		*1	I/O ₇ to I/O ₀ : Da	ta input/output	
73	81	RES	Reset circuit	A ₁₈ to A ₀ : Ad	dress input	
77	85	XTAL	Oscillation circuit *2		ip enable	
78	86	EXTAL	- Joseph Chicult		tput enable	
Othe	r pins	N.C. (OPEN)		WE: Wr	ite enable	

Notes: 1. A reset oscillation stabilization time (t_{osc1}) of at least 10 ms is required.

- 2. A 12 MHz crystal resonator should be used.
- 3. The V_{CL} pin should be connected to V_{SS} by using a capacitor of 0.47 μF (preliminary).

This figure shows pin assignments, and does not show the entire socket adapter circuit.

Figure 19-81 H8S/2329F-ZTAT Socket Adapter Pin Assignments

19.31.3 Programmer Mode Operation

Table 19-61 shows how the different operating modes are set when using programmer mode, and table 19-62 lists the commands used in programmer mode. Details of each mode are given below.

Memory Read Mode: Memory read mode supports byte reads.

Auto-Program Mode: Auto-program mode supports programming of 128 bytes at a time. Status polling is used to confirm the end of auto-programming.

Auto-Erase Mode: Auto-erase mode supports automatic erasing of the entire flash memory. Status polling is used to confirm the end of auto-erasing.

Status Read Mode: Status polling is used for auto-programming and auto-erasing, and normal termination can be confirmed by reading the I/O₆ signal. In status read mode, error information is output if an error occurs.

Table 19-61 Settings for Each Operating Mode in Programmer Mode

Pin Names

Mode	CE	ŌĒ	WE	I/O ₇ to I/O ₀	A ₁₈ to A ₀
Read	L	L	Н	Data output	Ain
Output disable	L	Н	Н	Hi-z	Х
Command write	L	Н	L	Data input	Ain*2
Chip disable*1	Н	Х	Х	Hi-z	X

Legend:

H: High level

L: Low level

Hi-z: High impedance

X: Don't care

Notes: 1. Chip disable is not a standby state; internally, it is an operation state.

2. Ain indicates that there is also address input in auto-program mode.

Table 19-62 Programmer Mode Commands

Number		1st Cycle				2nd Cycle		
Command Name	of Cycles	Mode	Address	Data	Mode	Address	Data	
Memory read mode	1 + n	Write	Х	H'00	Read	RA	Dout	
Auto-program mode	129	Write	Х	H'40	Write	PA	Din	
Auto-erase mode	2	Write	Х	H'20	Write	Х	H'20	
Status read mode	2	Write	Х	H'71	Write	Х	H'71	

Legend:

RA: Read address

PA: Program address

Notes: 1. In auto-program mode, 129 cycles are required for command writing by a simultaneous 128-byte write.

2. In memory read mode, the number of cycles depends on the number of address write cycles (n).

19.31.4 Memory Read Mode

- After the end of an auto-program, auto-erase, or status read operation, the command wait state
 is entered. To read memory contents, a transition must be made to memory read mode by
 means of a command write before the read is executed.
- Command writes can be performed in memory read mode, just as in the command wait state.
- Once memory read mode has been entered, consecutive reads can be performed.
- After power-on, memory read mode is entered.

Table 19-63 AC Characteristics in Memory Read Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit
Command write cycle	t _{nxtc}	20	_	μs
CE hold time	t _{ceh}	0	_	ns
CE setup time	t _{ces}	0	_	ns
Data hold time	t _{dh}	50	_	ns
Data setup time	t _{ds}	50	_	ns
Write pulse width	t _{wep}	70	_	ns
WE rise time	t _r	_	30	ns
WE fall time	t_{\scriptscriptstylef}	_	30	ns

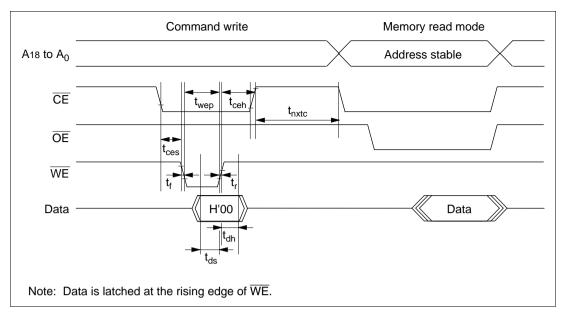


Figure 19-82 Memory Read Mode Timing Waveforms after Command Write

Table 19-64 AC Characteristics when Entering Another Mode from Memory Read Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	_
CE setup time	t _{ces}	0	_	ns	_
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t_{wep}	70	_	ns	
WE rise time	t _r	_	30	ns	_
WE fall time	t _f	_	30	ns	

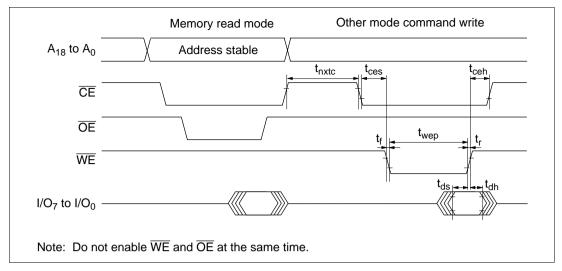


Figure 19-83 Timing Waveforms when Entering Another Mode from Memory Read Mode

Table 19-65 AC Characteristics in Memory Read Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Access time	t _{acc}	_	20	μs	
CE output delay time	t _{ce}	_	150	ns	
OE output delay time	t _{oe}	_	150	ns	
Output disable delay time	t _{df}	_	100	ns	
Data output hold time	t _{oh}	5		ns	_

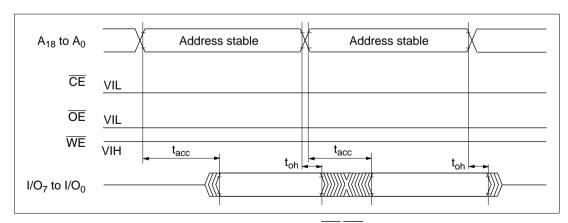


Figure 19-84 Timing Waveforms for $\overline{\text{CE}}/\overline{\text{OE}}$ Enable State Read

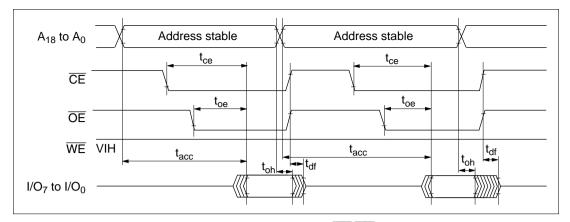


Figure 19-85 Timing Waveforms for CE/OE Clocked Read

19.31.5 Auto-Program Mode

- In auto-program mode, 128 bytes are programmed simultaneously. For this purpose, 128 consecutive byte data transfers should be performed.
- A 128-byte data transfer must be performed even if writing fewer than 128 bytes; in this case, H'FF data must be written to the extra addresses.
- The lower 7 bits of the transfer address must be held low. If an invalid address is input, memory programming will be started but a programming error will occur.
- Memory address transfer is executed in the second cycle (figure 19-86). Do not perform transfer later than the second cycle.
- Do not perform a command write during a programming operation.
- Perform one auto-programming operation for a 128-byte block for each address. One or more
 additional programming operations cannot be carried out on address blocks that have already
 been programmed.
- Confirm normal end of auto-programming by checking I/O₆. Alternatively, status read mode
 can also be used for this purpose (the I/O₇ status polling pin is used to identify the end of an
 auto-program operation).
- Status polling I/O₆ and I/O₇ information is retained until the next command write. As long as the next command write has not been performed, reading is possible by enabling $\overline{\text{CE}}$ and $\overline{\text{OE}}$.

AC Characteristics

Table 19-66 AC Characteristics in Auto-Program Mode (Conditions: V_{CC} = 5.0 V ±10%, V_{SS} = 0 V, T_a = 25°C ±5°C)

Item	Symbol	Min	Max	Unit
Command write cycle	t _{nxtc}	20	_	μs
CE hold time	t _{ceh}	0	_	ns
CE setup time	t _{ces}	0	_	ns
Data hold time	t _{dh}	50	_	ns
Data setup time	t _{ds}	50	_	ns
Write pulse width	t _{wep}	70	_	ns
Status polling start time	t _{wsts}	1	_	ms
Status polling access time	t _{spa}	_	150	ns
Address setup time	t _{as}	0	_	ns
Address hold time	t _{ah}	60	_	ns
Memory write time	t _{write}	1	3000	ms
WE rise time	t _r	_	30	ns
WE fall time	t _f	_	30	ns

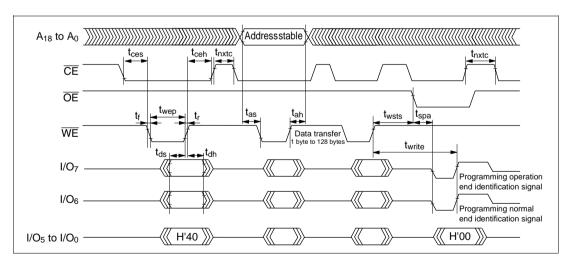


Figure 19-86 Auto-Program Mode Timing Waveforms

19.31.6 Auto-Erase Mode

- Auto-erase mode supports only total memory erasing.
- Do not perform a command write during auto-erasing.
- Confirm normal end of auto-erasing by checking I/O6. Alternatively, status read mode can also be used for this purpose (the I/O7 status polling pin is used to identify the end of an auto-erase operation).
- Status polling I/O6 and I/O7 pin information is retained until the next command write. As long
 as the next command write has not been performed, reading is possible by enabling \(\overline{CE}\) and
 \(\overline{OE}\).

AC Characteristics

Table 19-67 AC Characteristics in Auto-Erase Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t_{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t_{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
Status polling start time	t _{ests}	1	_	ms	
Status polling access time	t _{spa}	_	150	ns	
Memory erase time	t _{erase}	100	40000	ms	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	

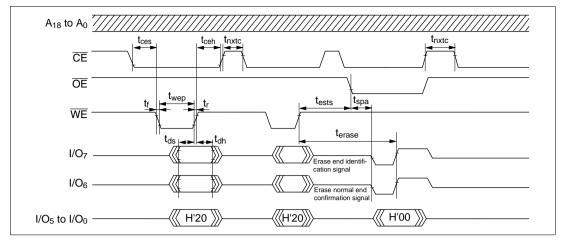


Figure 19-87 Auto-Erase Mode Timing Waveforms

19.31.7 Status Read Mode

- Status read mode is used to identify what type of abnormal end has occurred. Use this mode when an abnormal end occurs in auto-program mode or auto-erase mode.
- The return code is retained until a command write for other than status read mode is performed.

Table 19-68 AC Characteristics in Status Read Mode (Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$)

Item	Symbol	Min	Max	Unit	
Command write cycle	t _{nxtc}	20	_	μs	
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
OE output delay time	t _{oe}	_	150	ns	
Disable delay time	t _{df}	_	100	ns	
CE output delay time	t _{ce}	_	150	ns	
WE rise time	t _r	_	30	ns	
WE fall time	t _f	_	30	ns	
	-1			•••	

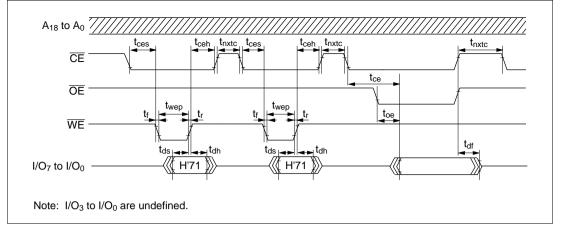


Figure 19-88 Status Read Mode Timing Waveforms

Table 19-69 Status Read Mode Return Commands

Pin Name	I/O ₇	I/O ₆	I/O ₅	I/O ₄	I/O ₃	I/O ₂	I/O ₁	I/O ₀
Attribute	Normal end identification	Command error	Program- ming error	Erase error	_	_	Program- ming or erase count exceeded	Effective address error
Initial value	0	0	0	0	0	0	0	0
Indications	Normal end: 0	Command error: 1	Program- ming	Erase error: 1	_	_	Count exceeded: 1	
	Abnormal end: 1	Otherwise: 0	error: 1 Otherwise: 0	Otherwise: 0			Otherwise: 0	error: 1 Otherwise: 0

Note: I/O₂ and I/O₃ are undefined.

19.31.8 Status Polling

- The I/O_7 status polling flag indicates the operating status in auto-program or auto-erase mode.
- The I/O₆ status polling flag indicates a normal or abnormal end in auto-program or auto-erase mode.

Table 19-70 Status Polling Output Truth Table

Pin Names	Internal Operation in Progress	Abnormal End	_	Normal End
I/O ₇	0	1	0	1
I/O ₆	0	0	1	1
I/O ₀ to I/O ₅	0	0	0	0

19.31.9 Programmer Mode Transition Time

Commands cannot be accepted during the oscillation stabilization period or the programmer mode setup period. After the programmer mode setup time, a transition is made to memory read mode.

Table 19-71 Command Wait State Transition Time Specifications

Item	Symbol	Min	Max	Unit	
Standby release (oscillation stabilization time)	t _{osc1}	30	_	ms	
Programmer mode setup time	$t_{\sf bmv}$	10	_	ms	
V _{cc} hold time	t_{dwn}	0	_	ms	

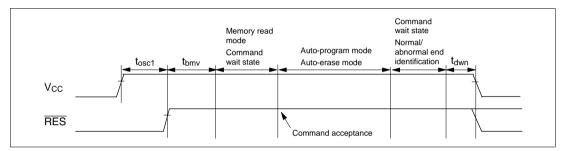


Figure 19-89 Oscillation Stabilization Time, Programmer Mode Setup Time, and Power Supply Fall Sequence

19.31.10 Notes On Memory Programming

- When programming addresses which have previously been programmed, carry out autoerasing before auto-programming.
- When performing programming using writer mode on a chip that has been programmed/erased
 in an on-board programming mode, auto-erasing is recommended before carrying out autoprogramming.
- Notes: 1. The flash memory is initially in the erased state when the device is shipped by Hitachi. For other chips for which the erasure history is unknown, it is recommended that autoerasing be executed to check and supplement the initialization (erase) level.
 - Auto-programming should be performed once only on the same address block.
 Additional programming cannot be carried out on address blocks that have already been programmed.

19.32 Flash Memory Programming and Erasing Precautions

Precautions concerning the use of on-board programming mode, the RAM emulation function, and programmer mode are summarized below.

Use the specified voltages and timing for programming and erasing: Applied voltages in excess of the rating can permanently damage the device. Use a PROM programmer that supports the Hitachi microcomputer device type with 512-kbyte on-chip flash memory (FZTAT512V5A).

Do not select the HN27C4096 setting for the PROM programmer, and only use the specified socket adapter. Failure to observe these points may result in damage to the device.

Powering on and off: When applying or disconnecting V_{CC} power, fix the \overline{RES} pin low and place the flash memory in the hardware protection state.

The power-on and power-off timing requirements should also be satisfied in the event of a power failure and subsequent recovery.

Use the recommended algorithm when programming and erasing flash memory: The recommended algorithm enables programming and erasing to be carried out without subjecting the device to voltage stress or sacrificing program data reliability. When setting the P1 or E1 bit in FLMCR1 or P2 or E2 bit in FLMCR2, the watchdog timer should be set beforehand as a precaution against program runaway, etc.

Notes on setting and clearing the SWE1 and SWE2 bits: Set or Clear the SWE1 and SWE2 bits before executing a program in flash memory. Wait for at least 100 (µs after clearing the SWE1 and SWE2 bits before executing a program or reading data in flash memory.)

When the SWE1 and SWE2 bits are set, data in flash memory can be rewritten, but when SWE1 = 1, addresses H'000000 to H'03FFFF in flash memory can only be read in program-verify or erase-verify mode, also when SWE 2 = 1, addresses H'040000 to H'07FFFF (H'05FFFF)* in flash memory can only be read in program-verify or erase-verify mode. Access the corresponding addresses in flash memory only for verify operations (verification during programming/erasing).

Do not clear the SWE1 and SWE2 bits during programming/erasing/verifying.

Similarly, when using the RAM emulation function, the SWE1 bit must be cleared before executing program or reading data in flash memory.

However, the RAM area overlapping flash memory space can be read and written to regardless of whether the SWE1 bit is set or cleared.

Note: * Addresses H'040000 to H'05FFFF are in the H8S/2395.

Do not use interrupts while flash memory is being programmed or erased: When flash memory is programmed or erased, all interrupt requests, including NMI, should be disabled to give priority to program/erase operations.

Do not perform additional programming. Erase the memory before reprogramming: In onboard programming, perform only one programming operation on a 128-byte programming unit block. In programmer mode, too, perform only one programming operation on a 128-byte programming unit block. Programming should be carried out with the entire programming unit block erased.

Before programming, check that the chip is correctly mounted in the PROM programmer: Overcurrent damage to the device can result if the index marks on the PROM programmer socket, socket adapter, and chip are not correctly aligned.

Do not touch the socket adapter or chip during programming: Touching either of these can cause contact faults and write errors.

Section 20 Clock Pulse Generator

20.1 Overview

The H8S/2357 Series has a built-in clock pulse generator (CPG) that generates the system clock (\emptyset) , the bus master clock, and internal clocks.

The clock pulse generator consists of an oscillator circuit, a duty adjustment circuit, a medium-speed clock divider, and a bus master clock selection circuit.

20.1.1 Block Diagram

Figure 20-1 shows a block diagram of the clock pulse generator.

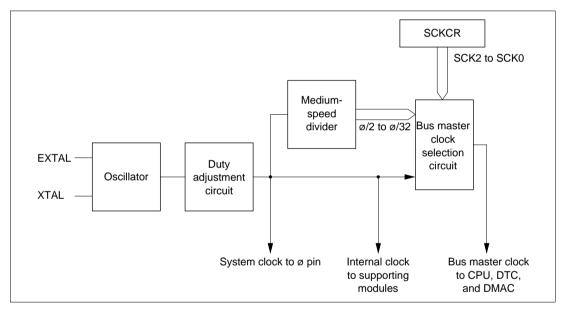


Figure 20-1 Block Diagram of Clock Pulse Generator

20.1.2 Register Configuration

The clock pulse generator is controlled by SCKCR. Table 20-1 shows the register configuration.

Table 20-1 Clock Pulse Generator Register

Name	Abbreviation	R/W	Initial Value	Address*
System clock control register	SCKCR	R/W	H'00	H'FF3A

Note:* Lower 16 bits of the address.

20.2 Register Descriptions

20.2.1 System Clock Control Register (SCKCR)

Bit	:	7	6	5	4	3	2	1	0
		PSTOP	_	_	_	_	SCK2	SCK1	SCK0
Initial va	alue :	0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	—/(R/W)*	_	_	R/W	R/W	R/W

SCKCR is an 8-bit readable/writable register that performs ø clock output control and medium-speed mode control.

SCKCR is initialized to H'00 by a reset and in hardware standby mode. It is not initialized in software standby mode.

Note: * R/W in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398.

Bit 7—ø Clock Output Disable (PSTOP): Controls ø output.

		Description									
Bit 7 PSTOP	Normal Operation	Sleep Mode	Software Standby Mode	Hardware Standby Mode							
0	ø output (initial value)	ø output	Fixed high	High impedance							
1	Fixed high	Fixed high	Fixed high	High impedance							

Bit 6—Reserved: In the H8S/2357 and H8S/2352, this bit can be read or written to, but only 0 should be written. This bit is reserved in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398. Only 0 should be written to this bit.

Bit 5—Reserved: This bit cannot be modified and is always read as 0.

Bits 4 and 3—Reserved: These bits cannot be modified and are always read as 0.

Bits 2 to 0—System Clock Select 2 to 0 (SCK2 to SCK0): These bits select the clock for the bus master.

Bit 2	Bit 1	Bit 0		
SCK2	SCK1	SCK0	Description	
0	0	0	Bus master is in high-speed mode	(Initial value)
		1	Medium-speed clock is ø/2	
	1	0	Medium-speed clock is ø/4	
		1	Medium-speed clock is ø/8	
1	0	0	Medium-speed clock is ø/16	
		1	Medium-speed clock is ø/32	
	1	_	_	

20.3 Oscillator

Clock pulses can be supplied by connecting a crystal resonator, or by input of an external clock.

20.3.1 Connecting a Crystal Resonator

Circuit Configuration: A crystal resonator can be connected as shown in the example in figure 20-2. Select the damping resistance R_d according to table 20-2. An AT-cut parallel-resonance crystal should be used.

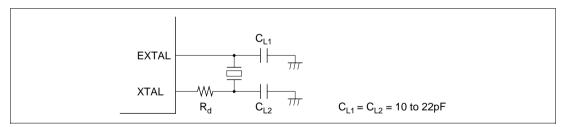


Figure 20-2 Connection of Crystal Resonator (Example)

Table 20-2 Damping Resistance Value

Frequency (MHz)	2	4	8	10	12	16	20
R _d ()	1k	500	200	0	0	0	0

Crystal Resonator: Figure 20-3 shows the equivalent circuit of the crystal resonator. Use a crystal resonator that has the characteristics shown in table 20-3 and the same resonance frequency as the system clock (\emptyset).

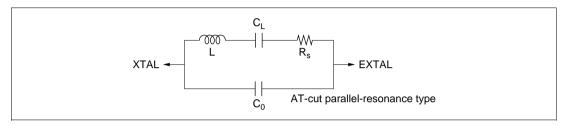


Figure 20-3 Crystal Resonator Equivalent Circuit

Table 20-3 Crystal Resonator Parameters

Frequency (MHz)	2	4	8	10	12	16	20
R _s max ()	500	120	80	70	60	50	40
C ₀ max (pF)	7	7	7	7	7	7	7

Note on Board Design: When a crystal resonator is connected, the following points should be noted:

Other signal lines should be routed away from the oscillator circuit to prevent induction from interfering with correct oscillation. See figure 20-4.

When designing the board, place the crystal resonator and its load capacitors as close as possible to the XTAL and EXTAL pins.

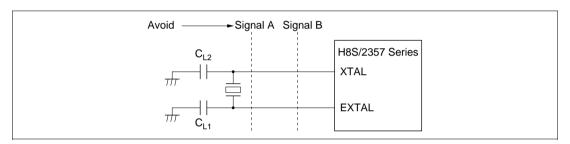


Figure 20-4 Example of Incorrect Board Design

20.3.2 External Clock Input

Circuit Configuration: An external clock signal can be input as shown in the examples in figure 20-5. If the XTAL pin is left open, make sure that stray capacitance is no more than 10 pF.

In example (b), make sure that the external clock is held high in standby mode.

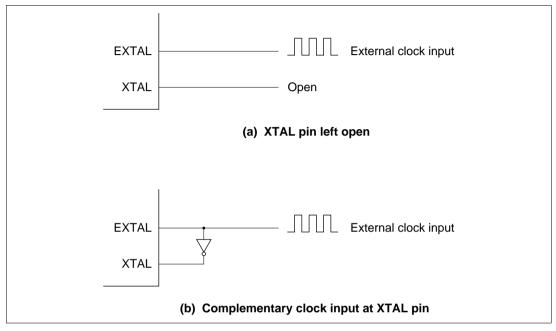


Figure 20-5 External Clock Input (Examples)

External Clock: The external clock signal should have the same frequency as the system clock (\emptyset) .

Table 20-4 and figure 20-6 show the input conditions for the external clock.

Table 20-4 External Clock Input Conditions

		to 5.5 V		10%					
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions		
External clock input low pulse width	t _{EXL}	40	_	20	_	ns	Figure 20-6		
External clock input high pulse width	t _{EXH}	40		20	_	ns	_		
External clock rise time	t _{EXr}	_	10	_	5	ns	_		
External clock fall time	t _{EXf}	_	10	_	5	ns			
Clock low pulse width	t _{Cl}	0.4	0.6	0.4	0.6	tovo	ø 5 MHz	Figure 22-4	

80

0.4

80

0.6

80

0.4

80

 t_{CH}

0.6

ø < 5 MHz

ø 5 MHz

ø < 5 MHz

ns

 $\mathbf{t}_{\mathrm{cyc}}$

ns

 $V_{cc} = 2.7 \text{ V}$ $V_{cc} = 5.0 \text{ V} \pm$

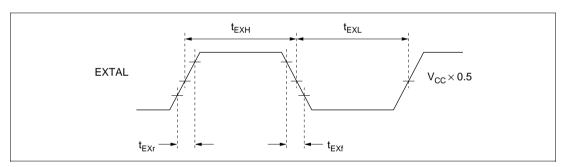


Figure 20-6 External Clock Input Timing

level

level

Clock high pulse width

20.4 Duty Adjustment Circuit

When the oscillator frequency is 5 MHz or higher, the duty adjustment circuit adjusts the duty cycle of the clock signal from the oscillator to generate the system clock (ϕ).

20.5 Medium-Speed Clock Divider

The medium-speed clock divider divides the system clock to generate $\emptyset/2$, $\emptyset/4$, $\emptyset/8$, $\emptyset/16$, and $\emptyset/32$.

20.6 Bus Master Clock Selection Circuit

The bus master clock selection circuit selects the system clock (\emptyset) or one of the medium-speed clocks (\emptyset /2, \emptyset /4, or \emptyset /8, \emptyset /16, and \emptyset /32) to be supplied to the bus master, according to the settings of the SCK2 to SCK0 bits in SCKCR.

Section 21 Power-Down Modes

21.1 Overview

In addition to the normal program execution state, the H8S/2357 Series has five power-down modes in which operation of the CPU and oscillator is halted and power dissipation is reduced. Low-power operation can be achieved by individually controlling the CPU, on-chip supporting modules, and so on.

The H8S/2357 Series operating modes are as follows:

- (1) High-speed mode
- (2) Medium-speed mode
- (3) Sleep mode
- (4) Module stop mode
- (5) Software standby mode
- (6) Hardware standby mode

Of these, (2) to (6) are power-down modes. Sleep mode is a CPU mode, medium-speed mode is a CPU and bus master mode, and module stop mode is an on-chip supporting module mode (including bus masters other than the CPU). A combination of these modes can be set.

After a reset, the H8S/2357 Series is in high-speed mode.

Table 21-1 shows the conditions for transition to the various modes, the status of the CPU, on-chip supporting modules, etc., and the method of clearing each mode.

Table 21-1 Operating Modes

Operating	Transition	Clearing			CPU	Me	odules	
Mode	Condition	Condition	Oscillator		Registers		Registers	I/O Ports
High speed mode	Control register		Functions	High speed	Functions	High speed	Functions	High speed
Medium- speed mode	Control register		Functions	Medium speed	Functions	High/ medium speed *		High speed
Sleep mode	Instruction	Interrupt	Functions	Halted	Retained	High speed	Functions	High speed
Module stop mode	Control register		Functions	High/ medium speed	Functions	Halted	Retained/ reset *2	Retained
Software standby mode	Instruction	External interrupt	Halted	Halted	Retained	Halted	Retained/ reset *2	Retained
Hardware standby mode	Pin		Halted	Halted	Undefined	Halted	Reset	High impedance

Notes: 1. The bus master operates on the medium-speed clock, and other on-chip supporting modules on the high-speed clock.

2. The SCI and A/D converter are reset, and other on-chip supporting modules retain their state.

21.1.1 Register Configuration

Power-down modes are controlled by the SBYCR, SCKCR, and MSTPCR registers. Table 21-2 summarizes these registers.

Table 21-2 Power-Down Mode Registers

Name	Abbreviation	R/W	Initial Value	Address*
Standby control register	SBYCR	R/W	H'08	H'FF38
System clock control register	SCKCR	R/W	H'00	H'FF3A
Module stop control register H	MSTPCRH	R/W	H'3F	H'FF3C
Module stop control register L	MSTPCRL	R/W	H'FF	H'FF3D

Note: * Lower 16 bits of the address.

21.2 Register Descriptions

21.2.1 Standby Control Register (SBYCR)

Bit	:	7	6	5	4	3	2	1	0
		SSBY	STS2	STS1	STS0	OPE	_	_	_
Initial va	lue :	0	0	0	0	1	0	0	0
R/W	:	R/W	R/W	R/W	R/W	R/W	_	_	R/W

SBYCR is an 8-bit readable/writable register that performs software standby mode control.

SBYCR is initialized to H'08 by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 7—Software Standby (SSBY): Specifies a transition to software standby mode. Remains set to 1 when software standby mode is released by an external interrupt, and a transition is made to normal operation. The SSBY bit should be cleared by writing 0 to it.

Bit 7 SSBY	Description	
0	Transition to sleep mode after execution of SLEEP instruction	(Initial value)
1	Transition to software standby mode after execution of SLEEP instruction	

Bits 6 to 4—Standby Timer Select 2 to 0 (STS2 to STS0): These bits select the time the MCU waits for the clock to stabilize when software standby mode is cleared by an external interrupt. With crystal oscillation, refer to table 21-4 and make a selection according to the operating frequency so that the standby time is at least 8 ms (the oscillation stabilization time). With an external clock, any selection can be made*.

Note: * Not available in the F-ZTAT version.

Bit 6 STS2	Bit 5 STS1	Bit 4 STS0	Description	
0	0	0	Standby time = 8192 states	(Initial value)
		1	Standby time = 16384 states	
	1	0	Standby time = 32768 states	
		1	Standby time = 65536 states	
1	0	0	Standby time = 131072 states	
		1	Standby time = 262144 states	
	1	0	Reserved	
		1	Standby time = 16 states*	

Note: * Not available in the F-ZTAT version

Bit 3—Output Port Enable (OPE): Specifies whether the output of the address bus and bus control signals (\overline{CSO} to $\overline{CS7}$, \overline{AS} , \overline{RD} , \overline{HWR} , \overline{LWR} , \overline{CAS}) is retained or set to the high-impedance state in software standby mode.

Bit 3 OPE	Description
0	In software standby mode, address bus and bus control signals are high-impedance
1	In software standby mode, address bus and bus control signals retain output state (Initial value)

Bits 2 and 1—Reserved: These bits cannot be modified and are always read as 0.

Bit 0—Reserved: This bit can be read or written to, but only 0 should be written.

21.2.2 System Clock Control Register (SCKCR)

Bit	:	7	6	5	4	3	2	1	0
		PSTOP	_	_	_	_	SCK2	SCK1	SCK0
Initial value:		0	0	0	0	0	0	0	0
R/W	:	R/W	R/W	—/(R/W)*	_	_	R/W	R/W	R/W

Note: * R/W in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398.

SCKCR is an 8-bit readable/writable register that performs ø clock output control and medium-speed mode control.

SCKCR is initialized to H'00 by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bit 7—ø Clock Output Disable (PSTOP): Controls ø output.

ח	esc	٠ri	nti	Λn
$\boldsymbol{\nu}$	せるし	, I I	vu	UH

Bit 7 PSTOP	Normal Operating Mode	Sleep Mode	Software Standby Mode	Hardware Standby Mode
0	ø output (initial value)	ø output	Fixed high	High impedance
1	Fixed high	Fixed high	Fixed high	High impedance

Bits 6—Reserved: This bit can be read or written to, but only 0 should be written.

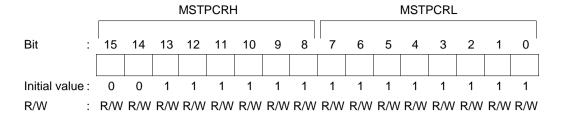
Bit 5—Reserved: In the H8S/2357 and H8S/2352, this bit cannot be modified and is always read as 0. Only 0 should be written. This bit is reserved in the H8S/2390, H8S/2392, H8S/2394, H8S/2395, H8S/2396, and H8S/2398. Only 0 should be written to this bit.

Bits 4 and 3—Reserved: These bits are always read as 0. Only 0 should be written to these bits.

Bits 2 to 0—System Clock Select (SCK2 to SCK0): These bits select the clock for the bus master.

Bit 2 SCK2	Bit 1 SCK1	Bit 0 SCK0	Description	
0	0	0	Bus master in high-speed mode	(Initial value)
		1	Medium-speed clock is ø/2	
	1	0	Medium-speed clock is ø/4	
		1	Medium-speed clock is ø/8	
1	0	0	Medium-speed clock is ø/16	
		1	Medium-speed clock is ø/32	
	1	_	_	

21.2.3 Module Stop Control Register (MSTPCR)



MSTPCR is a 16-bit readable/writable register that performs module stop mode control.

MSTPCR is initialized to H'3FFF by a reset and in hardware standby mode. It is not initialized in software standby mode.

Bits 15 to 0—Module Stop (MSTP 15 to MSTP 0): These bits specify module stop mode. See table 21-3 for the method of selecting on-chip supporting modules.

Bits 15 to 0 MSTP15 to MSTP0	Description
0	Module stop mode cleared
1	Module stop mode set

21.3 Medium-Speed Mode

When the SCK2 to SCK0 bits in SCKCR are set to 1, the operating mode changes to medium-speed mode as soon as the current bus cycle ends. In medium-speed mode, the CPU operates on the operating clock (\emptyset /2, \emptyset /4, \emptyset /8, \emptyset /16, or \emptyset /32) specified by the SCK2 to SCK0 bits. The bus masters other than the CPU (the DMAC and DTC) also operate in medium-speed mode. On-chip supporting modules other than the bus masters always operate on the high-speed clock (\emptyset).

In medium-speed mode, a bus access is executed in the specified number of states with respect to the bus master operating clock. For example, if $\emptyset/4$ is selected as the operating clock, on-chip memory is accessed in 4 states, and internal I/O registers in 8 states.

Medium-speed mode is cleared by clearing all of bits SCK2 to SCK0 to 0. A transition is made to high-speed mode and medium-speed mode is cleared at the end of the current bus cycle.

If a SLEEP instruction is executed when the SSBY bit in SBYCR is cleared to 0, a transition is made to sleep mode. When sleep mode is cleared by an interrupt, medium-speed mode is restored.

If a SLEEP instruction is executed when the SSBY bit in SBYCR is set to 1, a transition is made to software standby mode. When software standby mode is cleared by an external interrupt, medium-speed mode is restored.

When the \overline{RES} pin is driven low, a transition is made to the reset state, and medium-speed mode is cleared. The same applies in the case of a reset caused by overflow of the watchdog timer.

When the \overline{STBY} pin is driven low, a transition is made to hardware standby mode.

Figure 21-1 shows the timing for transition to and clearance of medium-speed mode.

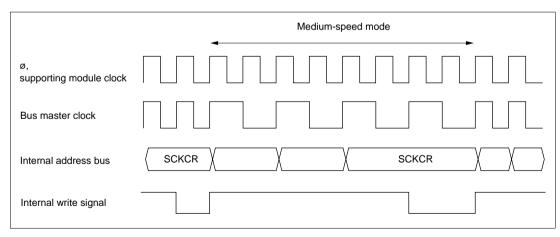


Figure 21-1 Medium-Speed Mode Transition and Clearance Timing

21.4 Sleep Mode

If a SLEEP instruction is executed when the SSBY bit in SBYCR is cleared to 0, the CPU enters sleep mode. In sleep mode, CPU operation stops but the contents of the CPU's internal registers are retained. Other supporting modules do not stop.

Sleep mode is cleared by a reset or any interrupt, and the CPU returns to the normal program execution state via the exception handling state. Sleep mode is not cleared if interrupts are disabled, or if interrupts other than NMI are masked by the CPU.

When the STBY pin is driven low, a transition is made to hardware standby mode.

21.5 Module Stop Mode

21.5.1 Module Stop Mode

Module stop mode can be set for individual on-chip supporting modules.

When the corresponding MSTP bit in MSTPCR is set to 1, module operation stops at the end of the bus cycle and a transition is made to module stop mode. The CPU continues operating independently.

Table 21-3 shows MSTP bits and the corresponding on-chip supporting modules.

When the corresponding MSTP bit is cleared to 0, module stop mode is cleared and the module starts operating at the end of the bus cycle. In module stop mode, the internal states of modules other than the SCI and A/D converter are retained.

After reset clearance, all modules other than DMAC and DTC are in module stop mode.

When an on-chip supporting module is in module stop mode, read/write access to its registers is disabled.

Do not make a transition to sleep mode with MSTPCR set to H'FFFF, as this will halt operation of the bus controller.

Table 21-3 MSTP Bits and Corresponding On-Chip Supporting Modules

Register	Bit	Module
MSTPCRH	MSTP15	DMA controller (DMAC)
	MSTP14	Data transfer controller (DTC)
	MSTP13	16-bit timer pulse unit (TPU)
	MSTP12	8-bit timer
	MSTP11	Programmable pulse generator (PPG)
	MSTP10	D/A converter
	MSTP9	A/D converter
	MSTP8	_
MSTPCRL	MSTP7	Serial communication interface (SCI) channel 2
	MSTP6	Serial communication interface (SCI) channel 1
	MSTP5	Serial communication interface (SCI) channel 0
	MSTP4	_
	MSTP3	_
	MSTP2	_
	MSTP1	_
	MSTP0	_

Note: Bits 8, and 4 to 0 can be read or written to, but do not affect operation.

21.5.2 Usage Notes

DMAC/DTC Module Stop: Depending on the operating status of the DMAC or DTC, the MSTP15 and MSTP14 bits may not be set to 1. Setting of the DMAC or DTC module stop mode should be carried out only when the respective module is not activated.

For details, refer to section 7, DMA Controller, and section 8, Data Transfer Controller.

On-Chip Supporting Module Interrupt: Relevant interrupt operations cannot be performed in module stop mode. Consequently, if module stop mode is entered when an interrupt has been requested, it will not be possible to clear the CPU interrupt source or the DMAC or DTC activation source. Interrupts should therefore be disabled before entering module stop mode.

Writing to MSTPCR: MSTPCR should only be written to by the CPU.

21.6 Software Standby Mode

21.6.1 Software Standby Mode

If a SLEEP instruction is executed when the SSBY bit in SBYCR is set to 1, software standby mode is entered. In this mode, the CPU, on-chip supporting modules, and oscillator all stop. However, the contents of the CPU's internal registers, RAM data, and the states of on-chip supporting modules other than the SCI and A/D converter, and I/O ports, are retained. Whether the address bus and bus control signals are placed in the high-impedance state or retain the output state can be specified by the OPE bit in SBYCR.

In this mode the oscillator stops, and therefore power dissipation is significantly reduced.

21.6.2 Clearing Software Standby Mode

Software standby mode is cleared by an external interrupt (NMI pin, or pins $\overline{IRQ0}$ to $\overline{IRQ2}$), or by means of the \overline{RES} pin or \overline{STBY} pin.

Clearing with an interrupt

When an NMI or IRQ0 to IRQ2 interrupt request signal is input, clock oscillation starts, and after the elapse of the time set in bits STS2 to STS0 in SYSCR, stable clocks are supplied to the entire H8S/2357 Series chip, software standby mode is cleared, and interrupt exception handling is started.

When clearing software standby mode with an IRQ0 to IRQ2 interrupt, set the corresponding enable bit to 1 and ensure that no interrupt with a higher priority than interrupts IRQ0 to IRQ2 is generated. Software standby mode cannot be cleared if the interrupt has been masked on the CPU side or has been designated as a DTC activation source.

• Clearing with the \overline{RES} pin

When the \overline{RES} pin is driven low, clock oscillation is started. At the same time as clock oscillation starts, clocks are supplied to the entire H8S/2357 Series chip. Note that the \overline{RES} pin must be held low until clock oscillation stabilizes. When the \overline{RES} pin goes high, the CPU begins reset exception handling.

Clearing with the STBY pin
 When the STBY pin is driven low, a transition is made to hardware standby mode.

21.6.3 Setting Oscillation Stabilization Time after Clearing Software Standby Mode

Bits STS2 to STS0 in SBYCR should be set as described below.

Using a Crystal Oscillator: Set bits STS2 to STS0 so that the standby time is at least 8 ms (the oscillation stabilization time).

Table 21-4 shows the standby times for different operating frequencies and settings of bits STS2 to STS0.

Table 21-4 Oscillation Stabilization Time Settings

STS2	STS1	STS0	Standby Time	20 MHz	16 MHz	12 MHz	10 MHz	8 MHz	6 MHz	4 MHz	2 MHz	Unit
0	0	0	8192 states	0.41	0.51	0.68	0.8	1.0	1.3	2.0	4.1	ms
		1	16384 states	0.82	1.0	1.3	1.6	2.0	2.7	4.1	8.2	_
	1	0	32768 states	1.6	2.0	2.7	3.3	4.1	5.5	8.2	16.4	_
		1	65536 states	3.3	4.1	5.5	6.6	8.2	10.9	16.4	32.8	_
1	0	0	131072 states	6.6	8.2	10.9	13.1	16.4	21.8	32.8	65.5	_
		1	262144 states	13.1	16.4	21.8	26.2	32.8	43.6	65.6	131.2	
	1	0	Reserved	_	_	_	_	_	_	_	_	
		1	16 states	8.0	1.0	1.3	1.6	2.0	2.7	4.0	8.0	μs

: Recommended time setting

Using an External Clock: Any value can be set. Normally, use of the minimum time is recommended.

Note: * The 16-state standby time cannot be used in the F-ZTAT version; a standby time of 8192 states or longer should be used.

21.6.4 Software Standby Mode Application Example

Figure 21-2 shows an example in which a transition is made to software standby mode at the falling edge on the NMI pin, and software standby mode is cleared at the rising edge on the NMI pin.

In this example, an NMI interrupt is accepted with the NMIEG bit in SYSCR cleared to 0 (falling edge specification), then the NMIEG bit is set to 1 (rising edge specification), the SSBY bit is set to 1, and a SLEEP instruction is executed, causing a transition to software standby mode.

Software standby mode is then cleared at the rising edge on the NMI pin.

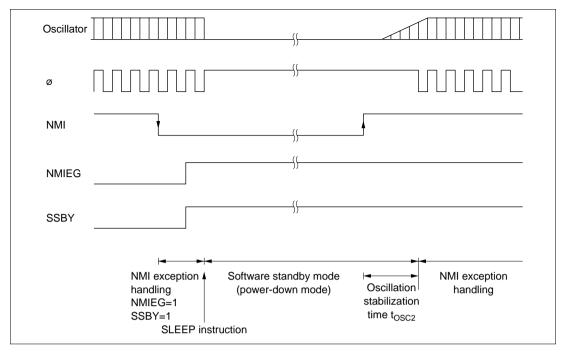


Figure 21-2 Software Standby Mode Application Example

21.6.5 Usage Notes

I/O Port Status: In software standby mode, I/O port states are retained. If the OPE bit is set to 1, the address bus and bus control signal output is also retained. Therefore, there is no reduction in current dissipation for the output current when a high-level signal is output.

Current Dissipation during Oscillation Stabilization Wait Period: Current dissipation increases during the oscillation stabilization wait period.

Write Data Buffer Function: The write data buffer function and software standby mode cannot be used at the same time. When the write data buffer function is used, the WDBE bit in BCRL should be cleared to 0 to cancel the write data buffer function before entering software standby mode. Also check that external writes have finished, by reading external addresses, etc., before executing a SLEEP instruction to enter software standby mode. See section 6.9, Write Data Buffer Function, for details of the write data buffer function.

21.7 Hardware Standby Mode

21.7.1 Hardware Standby Mode

When the STBY pin is driven low, a transition is made to hardware standby mode from any mode.

In hardware standby mode, all functions enter the reset state and stop operation, resulting in a significant reduction in power dissipation. As long as the prescribed voltage is supplied, on-chip RAM data is retained. I/O ports are set to the high-impedance state.

In order to retain on-chip RAM data, the RAME bit in SYSCR should be cleared to 0 before driving the \overline{STBY} pin low.

Do not change the state of the mode pins $(MD_2 \text{ to } MD_0)$ while the H8S/2357 Series is in hardware standby mode.

Hardware standby mode is cleared by means of the \overline{STBY} pin and the \overline{RES} pin. When the \overline{STBY} pin is driven high while the \overline{RES} pin is low, the reset state is set and clock oscillation is started. Ensure that the \overline{RES} pin is held low until the clock oscillator stabilizes (at least 8 ms—the oscillation stabilization time—when using a crystal oscillator). When the \overline{RES} pin is subsequently driven high, a transition is made to the program execution state via the reset exception handling state.

21.7.2 Hardware Standby Mode Timing

Figure 21-3 shows an example of hardware standby mode timing.

When the \overline{STBY} pin is driven low after the \overline{RES} pin has been driven low, a transition is made to hardware standby mode. Hardware standby mode is cleared by driving the \overline{STBY} pin high, waiting for the oscillation stabilization time, then changing the \overline{RES} pin from low to high.

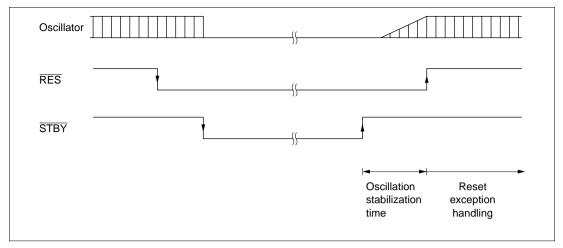


Figure 21-3 Hardware Standby Mode Timing (Example)

21.8 ø Clock Output Disabling Function

Output of the ø clock can be controlled by means of the PSTOP bit in SCKCR, and DDR for the corresponding port. When the PSTOP bit is set to 1, the ø clock stops at the end of the bus cycle, and ø output goes high. ø clock output is enabled when the PSTOP bit is cleared to 0. When DDR for the corresponding port is cleared to 0, ø clock output is disabled and input port mode is set. Table 21-5 shows the state of the ø pin in each processing state.

Table 21-5 Ø Pin State in Each Processing State

DDR	0	1	
PSTOP	_	0	1
Hardware standby mode	High impedance		
Software standby mode	High impedance	Fixed high	
Sleep mode	High impedance	ø output	Fixed high
Normal operating state	High impedance	ø output	Fixed high

Section 22 Electrical Characteristics (Preliminary)

22.1 Electrical Characteristics of Mask ROM Version (H8S/2398) and ROMless Versions (H8S/2394, H8S/2392, and H8S/2390)

22.1.1 Absolute Maximum Ratings

Table 22-1 Absolute Maximum Ratings

— Preliminary —

Item	Symbol	Value	Unit
Power supply voltage	V _{cc} *	-0.3 to +7.0	V
Input voltage (except port 4)	V_{in}	-0.3 to + V_{CC} +0.3	V
Input voltage (port 4)	V_{in}	-0.3 to AV _{CC} +0.3	V
Reference voltage	V_{ref}	-0.3 to AV _{CC} +0.3	V
Analog power supply voltage	AV _{cc}	-0.3 to +7.0	V
Analog input voltage	V _{AN}	-0.3 to AV _{cc} +0.3	V
Operating temperature	T _{opr}	Regular specifications: -20 to +75	°C
		Wide-range specifications: -40 to +85	°C
Storage temperature	T _{stg}	-55 to +125	°C

Caution: Permanent damage to the chip may result if absolute maximum ratings are exceeded.

Note: Do not supply the power supply voltage to the V_{cL} pin. Doing so could permanently damage the LSI. Connect an external capacitor between the V_{cL} pin and the ground pin.

22.1.2 DC Characteristics

Table 22-2 lists the DC characteristics.

Table 22-3 lists the permissible output currents.

Table 22-2 DC Characteristics

— Preliminary —

Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, Vref = 4.5 V to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}^{*1}$, Ta = -20 to $+75^{\circ}C$ (regular specifications), Ta = -40 to $+85^{\circ}C$ (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V _T	1.0	_	_	V	
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	V _T ⁺	_	_	$V_{\text{CC}} \times 0.7$	V	_
remage		$V_T^+ - V_T^-$	0.4	_	_	V	
Input high voltage	$\overline{\rm RES}, \overline{\rm STBY}, \\ {\rm NMI}, {\rm MD}_2 \\ {\rm to} \ {\rm MD}_0$	V _{IH}	V _{CC} - 0.7	_	V _{CC} + 0.3	V	_
	EXTAL		$V_{cc} \times 0.7$	_	$V_{cc} + 0.3$	V	
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃	-	2.0	_	V _{cc} + 0.3	V	_
	Port4	-	2.0	_	AV _{cc} + 0.3	V	
Input low voltage	$\overline{\text{RES}}$, $\overline{\text{STBY}}$, MD_2 to MD_0	V_{IL}	-0.3	_	0.5	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃		-0.3	_	0.8	V	
Output high	All output pins	V _{OH}	V _{cc} - 0.5	_	_	V	I _{OH} = -200 μA
voltage			3.5	_	_	V	I _{OH} = -1 mA
Output low	All output pins	V _{OL}	_	_	0.4	V	I _{OL} = 1.6 mA
voltage	Port 1, A to C	-	_	_	1.0	V	I _{OL} = 10 mA
Input leakage	RES		_	_	10.0	μΑ	V _{in} =
current	STBY, NMI, MD ₂ to MD ₀	-	_	_	1.0	μΑ	$^{-}$ 0.5 to V _{cc} – 0.5 V
	Port 4	-	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } AV_{CC} - 0.5 \text{ V}$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } V_{CC} - 0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	50	_	300	μΑ	V _{in} = 0 V
Input	RES	C_{in}	_	_	80	pF	$V_{in} = 0 V$
capacitance	NMI		_	_	50	pF	f = 1 MHz T
	All input pins except RES and NMI		_	_	15	pF	
Current dissipation*2	Normal operation	I _{CC} *4	_	TBD (5.0 V)	TBD)	mA	f = 20 MHz
	Sleep mode	_	_	TBD (5.0 V)	TBD	mA	f = 20 MHz
	Standby mode* ³		_	0.01	10	μΑ	T _a 50°C
			_	_	80		50°C < T _a
Analog power supply current	During A/D and D/A conversion	Al _{cc}	_	TBD (5.0 V)	2.0	mA	_
	Idle	_	_	TBD	5.0	μΑ	_
Reference current	During A/D and D/A conversion	Alcc	_	TBD (5.0 V)	3.0	mA	
	Idle			TBD	5.0	μΑ	
RAM standby v	oltage	V_{RAM}	2.0	_	_	V	

Notes: 1. If the A/D and D/A converters are not used,do not leave the AV_{CC}, AV_{SS}, and Vref pins open.

Connect AV_{cc} and Vref to V_{cc} pin, and connect AV_{ss} to V_{ss} pin.

- 2. Current dissipation values are for VIH min = V_{cc} -0.2 V and V_{IL} max = 0.5V with all output pins unloaded and the on-chip pull-up MOS in the off state.
- 3. The values are for V_{RAM} V $_{CC}$ < 4.5V, VIH min = V $_{CC}$ × 0.9, and V $_{IL}$ max = 0.3 V.
- 4. I_{cc} depends on V_{cc} and f as follows:

 $I_{\text{CC}} \text{ max} = \text{TBD (mA)} + \text{TBD (mA/(MHz \times V))} \times V_{\text{CC}} \times \text{f [normal mode]}$

 I_{cc} max = TBD (mA) + TBD (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-3 Permissible Output Currents

Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\% \text{ V}$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ to } AV_{CC}$, $V_{SS} = AV_{SS} = 0 \text{ V}$, $T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit
Permissible output	Port 1, A to C	I _{OL}	_	_	10	mA
low current (per pin)	Other output pins		_	_	2.0	mA
Permissible output low current (total)	Total of 32 pins including port 1 and A to C	\sum I _{OL}	_	_	80	mA
	Total of all output pins, including the above	_	_	_	120	mA
Permissible output high current (per pin)	All output pins	- I _{OH}	_	_	2.0	mA
Permissible output high current (total)	Total of all output pins	Σ –I _{OH}	_	_	40	mA

Notes: 1. To protect chip reliability, do not exceed the output current values in table 22-3.

2. When driving a darlington pair or LED directly, always insert a current-limiting resistor in the output line, as show in figures 22-1 and 22-2.

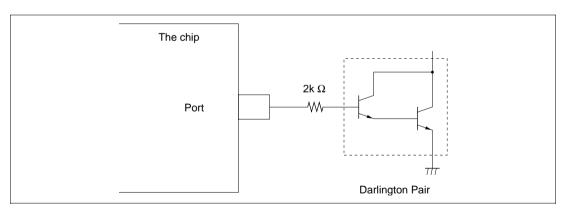


Figure 22-1 Darlington Pair Drive Circuit (Example)

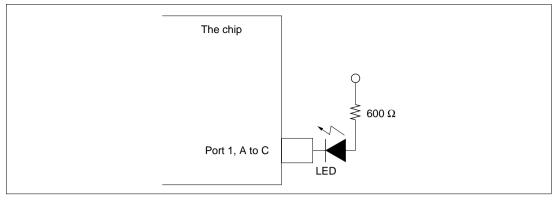


Figure 22-2 LED Drive Circuit (Example)

22.1.3 AC Characteristics

Figure 22-3 show, the test conditions for the AC characteristics.

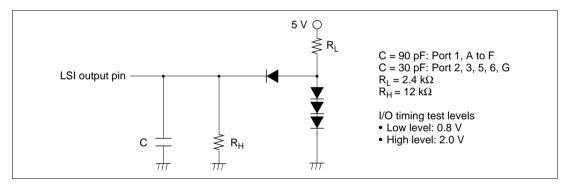


Figure 22-3 Output Load Circuit

(1) Clock Timing

Table 22-4 lists the clock timing

Table 22-4 Clock Timing

Condition: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 10$ to 20 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications),

			Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
Clock cycle time	t _{cyc}	50	100	ns	Figure 22-4
Clock high pulse width	t _{CH}	20	_	ns	
Clock low pulse width	t _{CL}	20	_	ns	
Clock rise time	t _{Cr}	_	5	ns	
Clock fall time	t _{Cf}	_	5	ns	
Clock oscillator setting time at reset (crystal)	t osc1	10	_	ms	Figure 22-5
Clock oscillator setting time in software standby (crystal)	t osc2	10	_	ms	Figure 21-2
External clock output stabilization delay time	t DEXT	500	_	μs	Figure 22-5

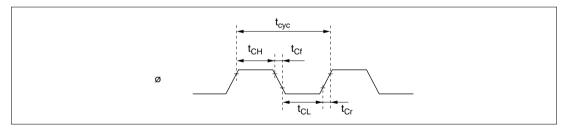


Figure 22-4 System Clock Timing

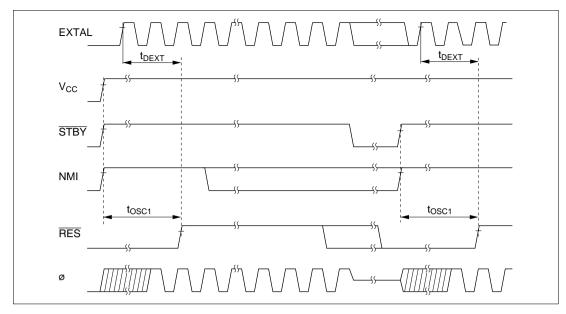


Figure 22-5 Oscillator Settling Timing

(2) Control Signal Timing

Table 22-5 lists the control signal timing.

Table 22-5 Control Signal Timing

Condition: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 10 \text{ to } 20 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

		(Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
RES setup time	t RESS	200	_	ns	Figure 22-6
RES pulse width	t _{RESW}	20	_	t _{cyc}	
NMI setup time	t _{NMIS}	150	_	ns	Figure 22-7
NMI hold time	t _{NMIH}	10	_		
NMI pulse width (exiting software standby mode)	t _{NMIW}	200	_	ns	
IRQ setup time	t IRQS	150	_	ns	
IRQ hold time	t _{IRQH}	10	_	ns	
IRQ pulse width (exiting software standby mode)	t _{IRQW}	200	_	ns	

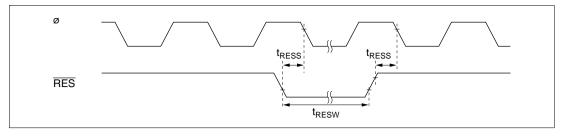


Figure 22-6 Reset Input Timing

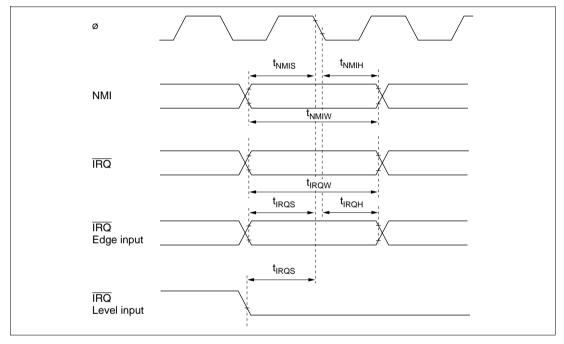


Figure 22-7 Interrupt Input Timing

(3) Bus Timing

Table 22-6 lists the bus timing.

Table 22-6 Bus Timing

Condition: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 10$ to 20 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications),

		Condition			Test
Item	Symbol	Min	Max	Unit	Conditions
Address delay time	t _{AD}	_	20	ns	Figure 22-8 to
Address setup time	t _{AS}	0.5 ×	_	ns	Figure 22-15
		t _{cyc} – 15			
Address hold time	t _{AH}	0.5×	_	ns	
=		t _{cyc} – 10			
Precharge time	t _{PCH}	1.5×	_	ns	
		$t_{cyc} - 20$			
CS delay time 1	t _{CSD1}	_	20	ns	
CS delay time 2	t _{CSD2}	_	20	ns	
CS delay time 3	t _{CSD3}	_	25	ns	
AS delay time	t _{ASD}	_	20	ns	
RD delay time 1	t _{RSD1}	_	20	ns	
RD delay time 2	t _{RSD2}	_	20	ns	
CAS delay time	t _{CASD}	_	20	ns	
Read data setup time	t _{RDS}	15		ns	
Read data hold time	t _{RDH}	0		ns	
Read data access time1	t _{ACC1}	_	1.0 ×	ns	
			t _{cyc} – 25		
Read data access time2	t _{ACC2}	_	1.5×	ns	
			t _{cyc} – 25		
Read data access time3	t _{ACC3}	_	2.0 ×	ns	
			$t_{cyc} - 25$		

		(Condition		Test	
Item	Symbol	Min Max		Unit	Conditions	
Read data access time 4	t _{ACC4}	_	2.5 × t _{cyc} – 25	ns	Figure 22-8 to Figure 22-15	
Read data access time 5	t _{ACC5}	_	$3.0 \times t_{\rm cyc} - 25$	ns		
WR delay time 1	t _{WRD1}	_	20	ns		
WR delay time 2	t _{WRD2}	_	20	ns		
WR pulse width 1	t _{WSW1}	$1.0 \times t_{\rm cyc} - 20$	_	ns		
WR pulse width 2	t _{WSW2}	1.5 × t _{cyc} – 20	_	ns		
Write data delay time	t _{WDD}		30	ns		
Write data setup time	t _{WDS}	0.5 × t _{cyc} – 20	_	ns		
Write data hold time	t _{WDH}	0.5 × t _{cyc} – 10	_	ns		
WR setup time	t _{wcs}	0.5 × t _{cyc} – 10	_	ns		
WR hold time	t _{WCH}	0.5 × t _{cyc} – 10	_	ns		
CAS setup time	t _{CSR}	0.5 × t _{cyc} – 10	_	ns	Figure 22-12	
WAIT setup time	t _{wts}	30		ns	Figure 22-10	
WAIT hold time	t _{WTH}	5		ns		
BREQ setup time	t _{BRQS}	30	_	ns	Figure 22-16	
BACK delay time	t BACD	_	15	ns		
Bus-floating time	t _{BZD}	_	50	ns		
BREQO delay time	t _{BRQOD}	_	30	ns	Figure 22-17	

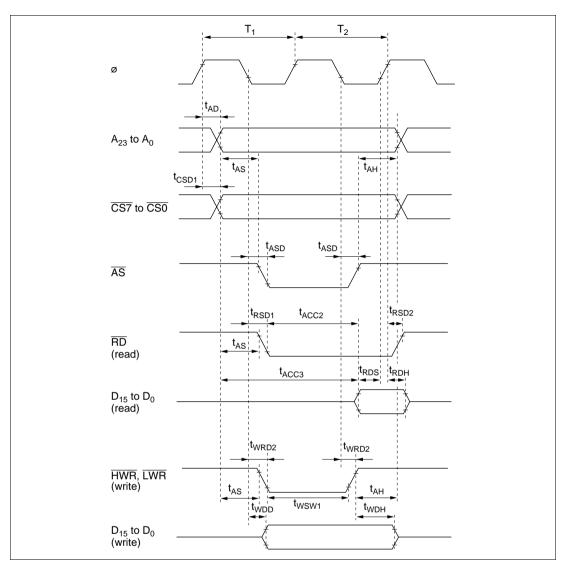


Figure 22-8 Basic Bus Timing (Two-State Access)

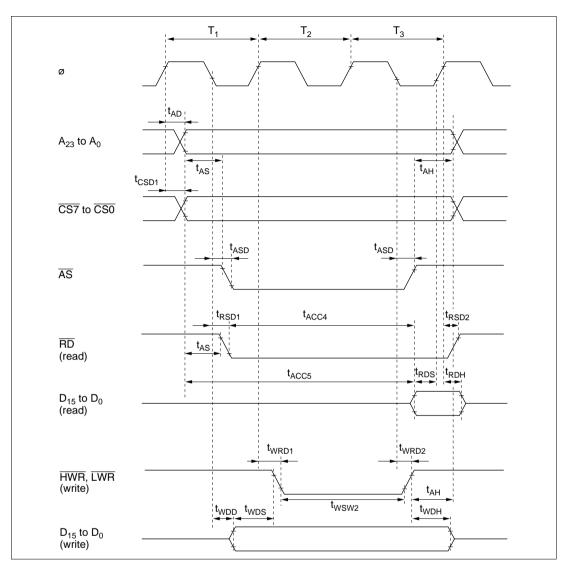


Figure 22-9 Basic Bus Timing (Three-State Access)

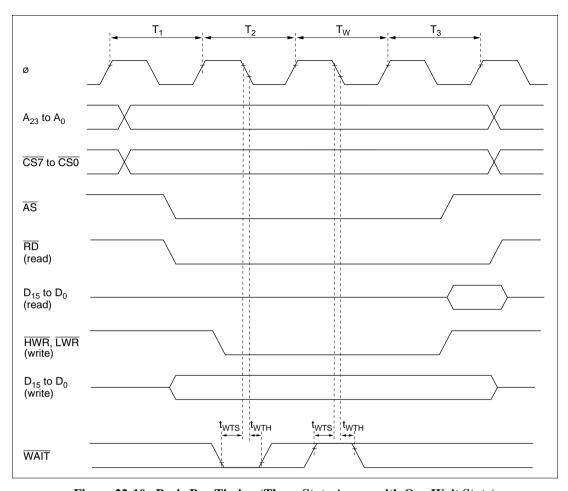


Figure 22-10 Basic Bus Timing (Three-State Access with One Wait State)

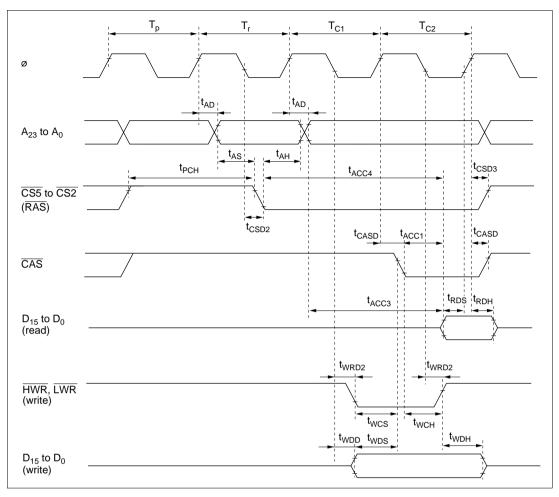


Figure 22-11 DRAM Bus Timing

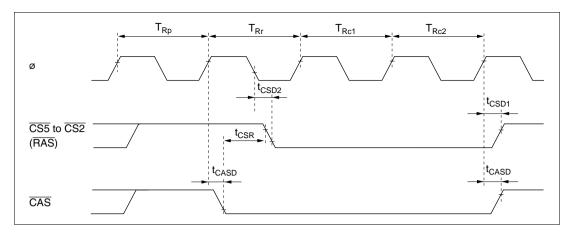


Figure 22-12 CAS-Before-RAS Refresh Timing

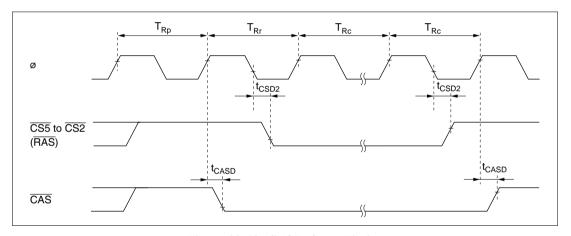


Figure 22-13 Self-Refresh Timing

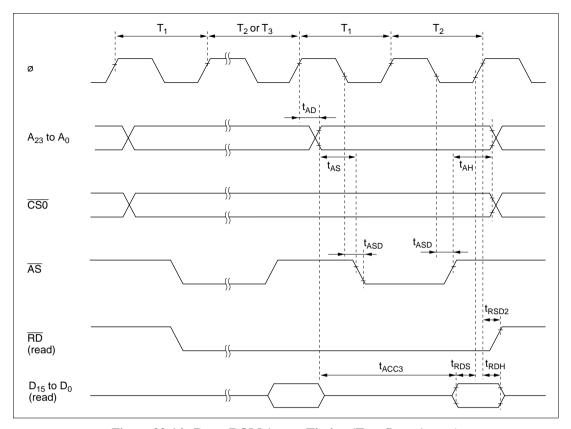


Figure 22-14 Burst ROM Access Timing (Two-State Access)

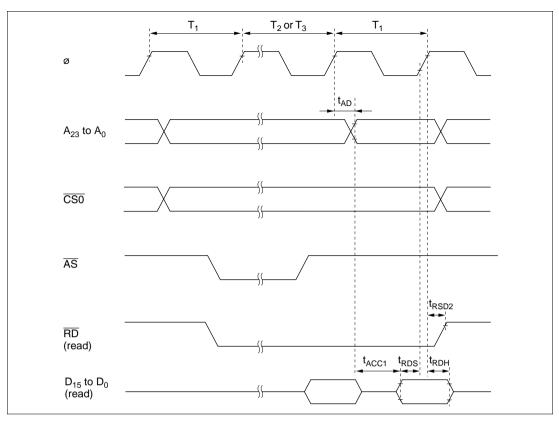


Figure 22-15 Burst ROM Access Timing (One-State Access)

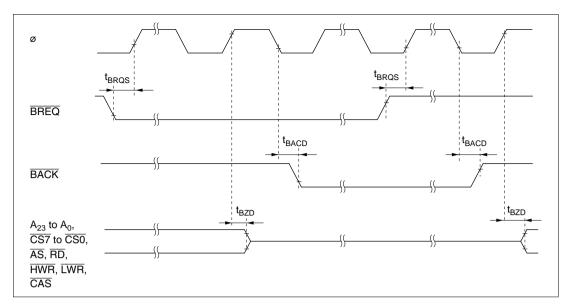


Figure 22-16 External Bus Release Timing

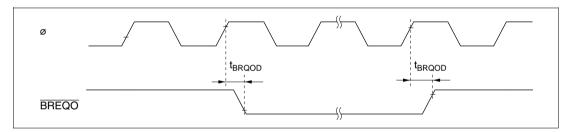


Figure 22-17 External Bus Request Output Timing

(4) DMAC Timing

Table 22-7 lists the DMAC timing.

Table 22-7 DMAC Timing

Condition: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 10 \text{ to } 20 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

			Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
DREQ setup time	t DRQS	30	_	ns	Figure 22-21
DREQ hold time	t DRQH	10	_		
TEND delay time	t _{TED}	_	20		Figure 22-20
DACK delay time 1	t DACD1	_	20	ns	Figure 22-18,
DACK delay time 2	t DACD2	_	20	<u>.</u>	Figure 22-19

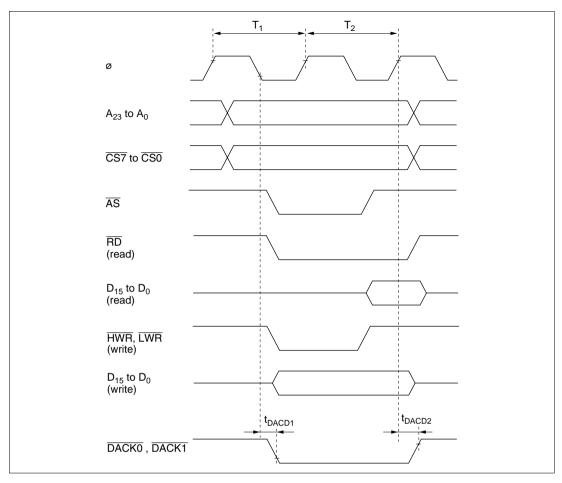


Figure 22-18 DMAC Single Address Transfer Timing (Two-State Access)

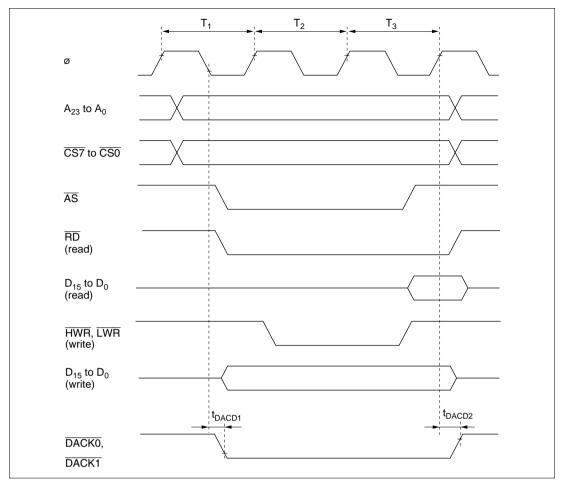


Figure 22-19 DMAC Single Address Transfer Timing (Three-State Access)

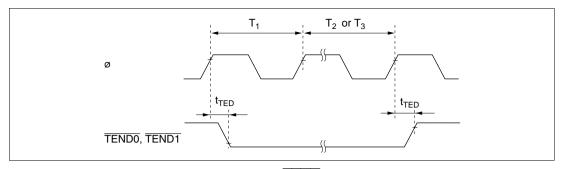


Figure 22-20 DMAC TEND Output Timing

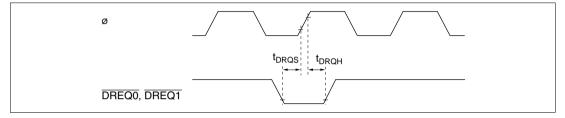


Figure 22-21 DMAC \overline{DREQ} Intput Timing

(5) Timing of On-Chip Supporting Modules

Table 22-8 lists the timing of on-chip supporting modules.

Table 22-8 Timing of On-Chip Supporting Modules

Condition: V_{CC} = 5.0 V \pm 10%, AV_{CC} = 5.0 V \pm 10%, V_{ref} = 4.5 V to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 10 \text{ to } 20 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

			Condition				Test
Item				Min	Max	Unit	Conditions
PORT	Γ Output data d	Output data delay time		_	50	ns	Figure 22-22
	Input data set	up time	t _{PWD}	30	_		
	Input data hol	d time	t _{PRH}	30	_		
PPG	Pulse output	delay time	t _{POD}	_	50	ns	Figure 22-23
TPU	Timer output	delay time	t TOCD	_	50	ns	Figure 22-24
	Timer input se	Timer input setup time		30	_		
	Timer clock input setup time		t _{TCKS}	30	_	ns	Figure 22-25
	Timer clock pulse width	Single edge	t _{TCKWH}	1.5	_	t _{cyc}	
		Both edges	t _{TCKWL}	2.5	_		
TMR	Timer output	delay time	t_{TMOD}	_	50	ns	Figure 22-26
	Timer reset input setup time		t_{TMRS}	30	_	ns	Figure 22-28
	Timer clock input setup time		t _{TMCS}	30	_	ns	Figure 22-27
	Timer clock pulse width	Single edge	t _{TMCWH}	1.5	_	t _{cyc}	Figure 22-27
		Both edges	t _{TMCWL}	2.5	_		

					Condition		Test Conditions
Item			Symbol	Min	Max	Unit	
SCI	Input clock cycle	Asynchro- nous	t _{Scyc}	4	_	t _{cyc}	Figure 22-29
		Synchro- nous	_	6	_		
	Input clock	oulse width	t _{SCKW}	0.4	0.6	t _{Scyc}	
	Input clock i	rise time	t _{SCKr}	_	1.5	t _{cyc}	
	Input clock fall time		t _{SCKf}	_	1.5		
	Transmit data delay time		t _{TXD}	_	50	ns	Figure 22-30
	Receive dat time (synchi	•	t _{RXS}	50	_	ns	
	Receive dat time (synchi		t _{RXH}	50	_	ns	
A/D con- verter	Trigger inputime	it setup	t _{TRGS}	30	_	ns	Figure 22-31

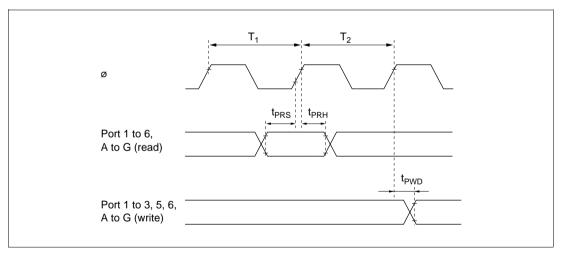


Figure 22-22 I/O Port Input/Output Timing

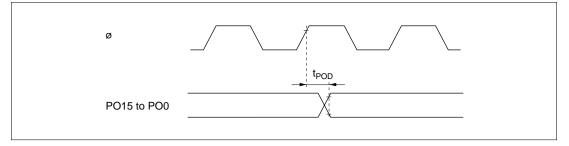


Figure 22-23 PPG Output Timing

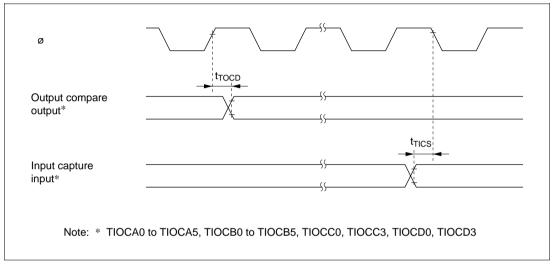


Figure 22-24 TPU Input/Output Timing

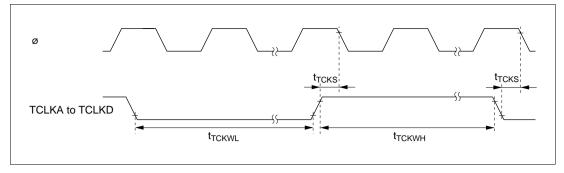


Figure 22-25 TPU Clock Input Timing

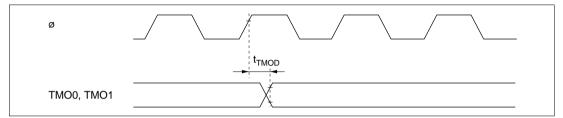


Figure 22-26 8-Bit Timer Output Timing

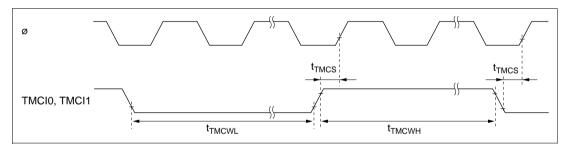


Figure 22-27 8-Bit Timer Clock Input Timing

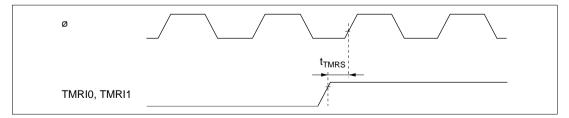


Figure 22-28 8-Bit Timer Reset Input Timing

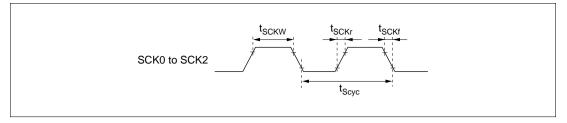


Figure 22-29 SCK Clock Input Timing

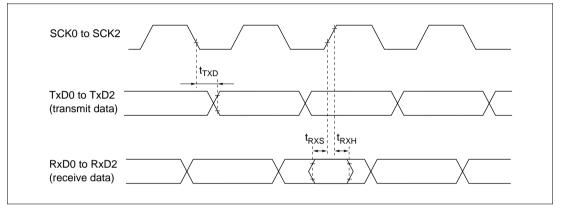


Figure 22-30 SCI Input/Output Timing (Clock Synchronous Mode)

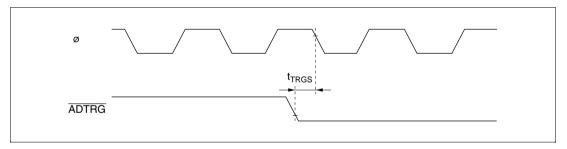


Figure 22-31 A/D Converter External Trigger Input Timing

22.1.4 A/D Conversion Characteristics

Table 22-9 lists the A/D conversion characteristics.

Table 22-9 A/D Conversion Characteristics

$$\begin{split} \text{Conditions: } & V_{\text{CC}} = AV_{\text{CC}} = 5.0 \text{ V} \pm 10\%, V_{\text{ref}} = 4.5 \text{ V to } AV_{\text{CC}}, V_{\text{SS}} = AV_{\text{SS}} = 0 \text{ V}, \\ & \varphi = 10 \text{ to } 20 \text{ MHz}, T_{\text{a}} = -20 \text{ to } +75^{\circ}\text{C (regular specifications)}, \\ & T_{\text{a}} = -40 \text{ to } +85^{\circ}\text{C (wide-range specifications)} \end{split}$$

Item	Min	Тур	Max	Unit
Resolution	10	10	10	bits
Conversion time	6.7	_	_	μS
Analog input capacitance	_	_	20	pF
Permissible signal-source impedance	_	_	10* ¹	ΚΩ
	_	_	5* ²	
Nonlinearity error	_	_	±3.5	LSB
Offset error	_	_	±3.5	LSB
Full-scale error	_	_	±3.5	LSB
Quantization error	_	_	±0.5	LSB
Absolute accuracy	_	_	±4.0	LSB

Notes: 1. \phi 12 MHz

2. φ > 12 MHz

22.1.5 D/A Conversion Characteristics

Table 22-10 lists the D/A conversion characteristics.

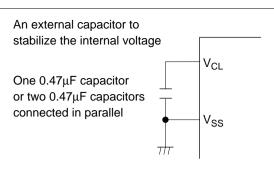
Table 22-10 D/A Conversion Characteristics

Conditions:
$$V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$$
, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\phi = 10$ to 20 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

Item	Min	Тур	Max	Unit	Test Conditions
Resolution	8	8	8	bits	_
Conversion time	_	_	10	μS	20-pF capacitive load
Absolute accuracy	_	±1.0	±1.5	LSB	$2M\Omega$ resistive load
	_	_	±1.0	LSB	$4M\Omega$ resistive load

22.2 Usage Note (internal voltage step down for the H8S/2398, H8S/2394, H8S/2392, and H8S/2390)

The H8S/2398, H8S/2394, H8S/2392, or H8S/2390 have a voltage step down circuit that automatically lowers the power supply voltage, inside the microcomputer, to an adequate level. A capacitor (one 0.47- μ F capacitor or two 0.47- μ F capacitors connected in parallel) should be connected between the V_{CL} pin (a pin for internal voltage step down circuit) and V_{SS} pin to stabilize the internal voltage. Figure 22-32 shows how to connect the capacitor. Do not connect the V_{CC} power-supply to the V_{CL} pin. Doing so could permanently damage the LSI. (Connect the V_{CC} power-supply to the V_{CC} pin, in the usual way.)



Do not connect the V_{CC} power-supply to the V_{CL} pin. Doing so could permanently damage the LSI. (Connect the V_{CC} power-supply to the other V_{CC} pin in the usual way.) Use a multilayer ceramic capacitor (one 0.47 μ F capacitor or two 0. 47μ F capacitors connected in parallel) for this circuit, and place it/them near the V_{CL} pin.

Figure 22-32 V_{CL} Capacitor Connection Method

22.3 Electrical Characteristics of F-ZTAT Versions (H8S/2398, H8S/2396, and H8S/2395) (Preliminary)

22.3.1 Absolute Maximum Ratings

Table 22-11 Absolute Maximum Ratings

— Preliminary —

Item	Symbol	Value	Unit
Power supply voltage	V _{CC} *1	-0.3 to +7.0	V
Input voltage (except port 4)	V _{in}	$-0.3 \text{ to + V}_{cc} + 0.3$	V
Input voltage (port 4)	V _{in}	-0.3 to AV _{CC} +0.3	V
Reference voltage	V_{ref}	-0.3 to AV _{cc} +0.3	V
Analog power supply voltage	AV _{cc}	-0.3 to +7.0	V
Analog input voltage	V_{AN}	-0.3 to AV _{CC} +0.3	V
Operating temperature	T _{opr}	Regular specifications: -20 to +75*2	°C
		Wide-range specifications: -40 to +85*2	°C
Storage temperature	T _{stg}	-55 to +125	°C

Caution: Permanent damage to the chip may result if absolute maximum ratings are exceeded.

Notes: 1. Do not supply the power supply voltage to the V_{CL} pin. Doing so could permanently damage the LSI. Connect an external capacitor between the V_{CL} pin and the ground pin.

 The operating temperature ranges for flash memory programming/erasing are as follows: Ta = 0 to TBD°C (regular specifications), Ta = 0 to TBD°C (wide-range specifications).

22.3.2 DC Characteristics

Table 22-12 lists the DC characteristics.

Table 22-13 lists the permissible output currents.

Table 22-12 DC Characteristics

— Preliminary —

Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, Vref = 4.5 V to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}^{*1}$, $Ta = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $Ta = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V_T^-	1.0	_	_	V	
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	V_{T}^{+}	_	_	$V_{\text{CC}}\times 0.7$	V	_
ronago	. 7 14 10 1 7 17	$V_T^+ - V_T^-$	0.4	_	_	V	
Input high voltage	$\overline{\text{RES}}$, $\overline{\text{STBY}}$, $\overline{\text{NMI}}$, $\overline{\text{MD}}_2$ to $\overline{\text{MD}}_0$	V_{IH}	V _{cc} – 0.7	_	V _{cc} + 0.3	V	_
	EXTAL		$V_{\text{cc}} \times 0.7$	_	$V_{cc} + 0.3$	V	
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃	_	2.0	_	V _{cc} + 0.3	V	
	Port4		2.0	_	$AV_{CC} + 0.3$	3 V	
Input low voltage	\overline{RES} , \overline{STBY} , MD_2 to MD_0	V_{IL}	-0.3	_	0.5	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃		-0.3	_	0.8	V	
Output high	All output pins	V _{OH}	V _{cc} - 0.5	_	_	V	I _{OH} = -200 μA
voltage			3.5	_	_	V	I _{OH} = -1 mA
Output low	All output pins	V_{OL}	_	_	0.4	V	$I_{OL} = 1.6 \text{ mA}$
voltage	Port 1, A to C		_	_	1.0	V	$I_{OL} = 10 \text{ mA}$
Input leakage	RES		_	_	10.0	μΑ	_ V _{in} =
current	$\overline{\text{STBY}}$, NMI, MD ₂ to MD ₀		_	_	1.0	μΑ	$^{-}$ 0.5 to V _{cc} $-$ 0.5 V
	Port 4	-	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to AV}_{CC} - 0.5 \text{ V}$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } V_{CC} - 0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	50	_	300	μΑ	$V_{in} = 0 V$
Input	RES	C_{in}	_	_	80	pF	$V_{in} = 0 V$
capacitance	NMI	_	_	_	50	pF	f = 1 MHz T
	All input pins except RES and NMI		_	_	15	pF	
Current dissipation*2	Normal operation	I _{CC} *4	_	TBD (5.0 V)	TBD)	mA	f = 20 MHz
	Sleep mode	_	_	TBD (5.0 V)	TBD	mA	f = 20 MHz
	Standby		_	0.01	10	μΑ	T _a 50°C
	mode*3		_	_	80		50°C < T _a
Analog power supply current	During A/D and D/A conversion	Alcc	_	TBD (5.0 V)	2.0	mA	
	Idle	_	_	TBD	5.0	μΑ	_
Reference current	During A/D and D/A conversion	Al _{cc}		TBD (5.0 V)	3.0	mA	
	Idle		_	TBD	5.0	μΑ	
RAM standby v	oltage	V_{RAM}	2.0	_	_	V	

Notes: 1. If the A/D and D/A converters are not used,do not leave the AV_{CC}, AV_{SS}, and Vref pins open.

Connect AV_{CC} and Vref to V_{CC} pin, and connect AV_{SS} to V_{SS} pin.

- 2. Current dissipation values are for VIH min = V_{cc} -0.2 V and V_{lL} max = 0.5V with all output pins unloaded and the on-chip pull-up MOS in the off state.
- 3. The values are for V_{RAM} V_{CC} < 4.5V, VIH min = $V_{CC} \times 0.9$, and V_{IL} max = 0.3 V.
- 4. I_{cc} depends on V_{cc} and f as follows:

 $I_{\text{CC}} \text{ max} = \text{TBD (mA)} + \text{TBD (mA/(MHz \times V))} \times V_{\text{CC}} \times \text{f [normal mode]}$

 I_{cc} max = TBD (mA) + TBD (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-13 Permissible Output Currents

Conditions:
$$V_{CC} = 5.0 \text{ V} \pm 10\% \text{ V}$$
, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ to } AV_{CC}$, $V_{SS} = AV_{SS} = 0 \text{ V}$, $T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit
Permissible output	Port 1, A to C	I _{OL}	_	_	10	mA
low current (per pin)	Other output pins		_	_	2.0	mA
Permissible output low current (total)	Total of 32 pins including port 1 and A to C	\sum I _{OL}	_	_	80	mA
	Total of all output pins, including the above	_	_	_	120	mA
Permissible output high current (per pin)	All output pins	-I _{OH}	_	_	2.0	mA
Permissible output high current (total)	Total of all output pins	Σ –I _{OH}	_	_	40	mA

Notes: 1. To protect chip reliability, do not exceed the output current values in table 22-13.

2. When driving a darlington pair or LED directly, always insert a current-limiting resistor in the output line, as show in figures 22-33 and 22-34.

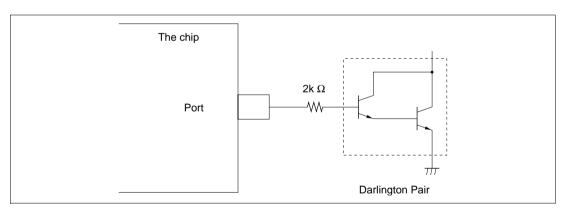


Figure 22-33 Darlington Pair Drive Circuit (Example)

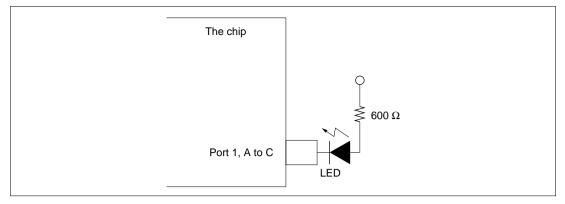


Figure 22-34 LED Drive Circuit (Example)

22.3.3 AC Characteristics

Figure 22-35 show, the test conditions for the AC characteristics.

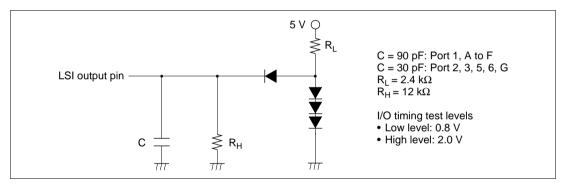


Figure 22-35 Output Load Circuit

(1) Clock Timing

Table 22-14 lists the clock timing

Table 22-14 Clock Timing

Condition: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 10$ to 20 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications),

			Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
Clock cycle time	t _{cyc}	50	100	ns	Figure 22-36
Clock high pulse width	t _{CH}	20	_	ns	
Clock low pulse width	t _{CL}	20	_	ns	
Clock rise time	t _{Cr}	_	5	ns	
Clock fall time	t _{Cf}	_	5	ns	
Clock oscillator setting time at reset (crystal)	t osc1	10	_	ms	Figure 22-37
Clock oscillator setting time in software standby (crystal)	t osc2	10	_	ms	Figure 21-2
External clock output stabilization delay time	t _{DEXT}	500	_	μs	Figure 22-37

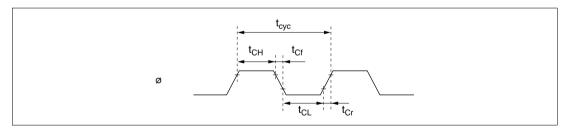


Figure 22-36 System Clock Timing

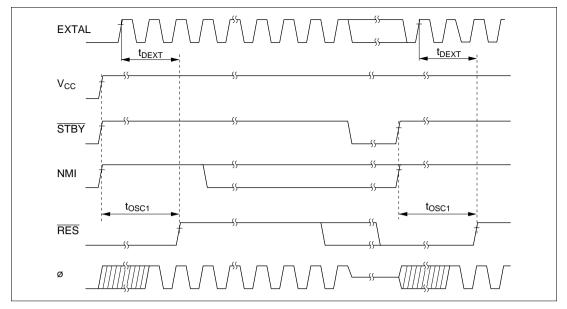


Figure 22-37 Oscillator Settling Timing

(2) Control Signal Timing

Table 22-15 lists the control signal timing.

Table 22-15 Control Signal Timing

Condition: V_{CC} = 5.0 V \pm 10%, AV_{CC} = 5.0 V \pm 10%, V_{ref} = 4.5 V to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 10 \text{ to } 20 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

		(Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
RES setup time	t _{RESS}	200	_	ns	Figure 22-38
RES pulse width	t _{RESW}	20	_	t _{cyc}	
NMI setup time	t _{NMIS}	150	_	ns	Figure 22-39
NMI hold time	t _{NMIH}	10	_		
NMI pulse width (exiting software standby mode)	t _{NMIW}	200	_	ns	
IRQ setup time	t _{IRQS}	150	_	ns	
IRQ hold time	t _{IRQH}	10	_	ns	
IRQ pulse width (exiting software standby mode)	t _{IRQW}	200	_	ns	

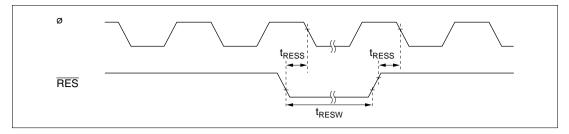


Figure 22-38 Reset Input Timing

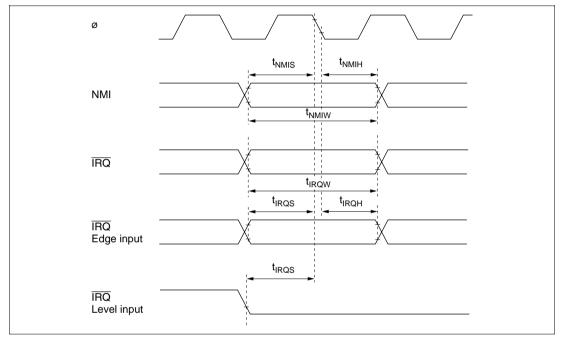


Figure 22-39 Interrupt Input Timing

(3) Bus Timing

Table 22-16 lists the bus timing.

Table 22-16 Bus Timing

Condition: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 10$ to 20 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications),

		(Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
Address delay time	t _{AD}	_	20	ns	Figure 22-40 to
Address setup time	t _{AS}	0.5 ×	_	ns	Figure 22-47
		t _{cyc} – 15			
Address hold time	t _{AH}	0.5×	_	ns	
		$t_{cyc} - 10$			
Precharge time	t _{PCH}	1.5×	_	ns	
_		$t_{\rm cyc} - 20$			
CS delay time 1	t _{CSD1}	_	20	ns	
CS delay time 2	t _{CSD2}	_	20	ns	
CS delay time 3	t _{CSD3}	_	25	ns	
AS delay time	t _{ASD}	_	20	ns	
RD delay time 1	t _{RSD1}	_	20	ns	
RD delay time 2	t _{RSD2}	_	20	ns	
CAS delay time	t _{CASD}	_	20	ns	
Read data setup time	t _{RDS}	15	_	ns	
Read data hold time	t _{RDH}	0	_	ns	
Read data access time1	t _{ACC1}	_	1.0 ×	ns	
			$t_{\rm cyc} - 25$		
Read data access time2	t ACC2	_	1.5×	ns	
			$t_{cyc} - 25$		
Read data access time3	t ACC3	_	2.0 ×	ns	
			$t_{cyc} - 25$		

		(Test		
Item	Symbol	Min	Max	Unit	Conditions
Read data access time 4	t _{ACC4}	_	2.5 × t _{cyc} – 25	ns	Figure 22-40 to Figure 22-47
Read data access time 5	t _{ACC5}	_	$3.0 \times t_{\rm cyc} - 25$	ns	
WR delay time 1	t _{WRD1}	_	20	ns	
WR delay time 2	t _{WRD2}	_	20	ns	
WR pulse width 1	t _{WSW1}	$1.0 \times t_{\rm cyc} - 20$	_	ns	
WR pulse width 2	t _{WSW2}	1.5 × t _{cyc} – 20	_	ns	
Write data delay time	t _{wdd}		30	ns	
Write data setup time	t _{WDS}	0.5 × t _{cyc} – 20	_	ns	
Write data hold time	t _{WDH}	0.5 × t _{cyc} – 10	_	ns	
WR setup time	t _{WCS}	0.5 × t _{cyc} – 10	_	ns	
WR hold time	t _{WCH}	0.5 × t _{cyc} – 10	_	ns	
CAS setup time	t _{CSR}	$0.5 \times t_{\rm cyc} - 10$	_	ns	Figure 22-44
WAIT setup time	t _{wts}	30	-	ns	Figure 22-42
WAIT hold time	t _{WTH}	5	_	ns	
BREQ setup time	t BRQS	30	_	ns	Figure 22-48
BACK delay time	t _{BACD}	_	15	ns	
Bus-floating time	t _{BZD}	_	50	ns	
BREQO delay time	t BRQOD	_	30	ns	Figure 22-49

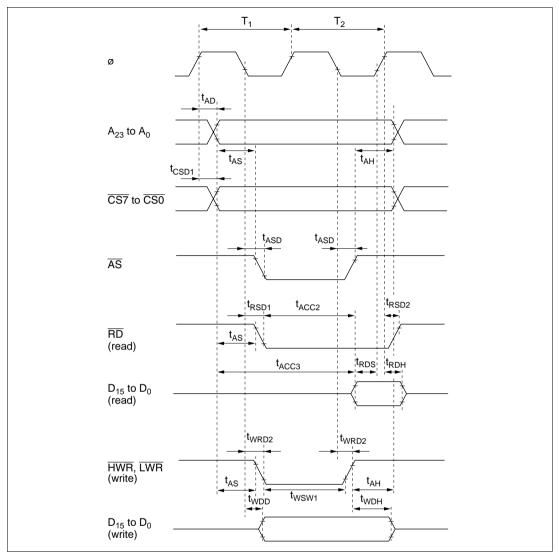


Figure 22-40 Basic Bus Timing (Two-State Access)

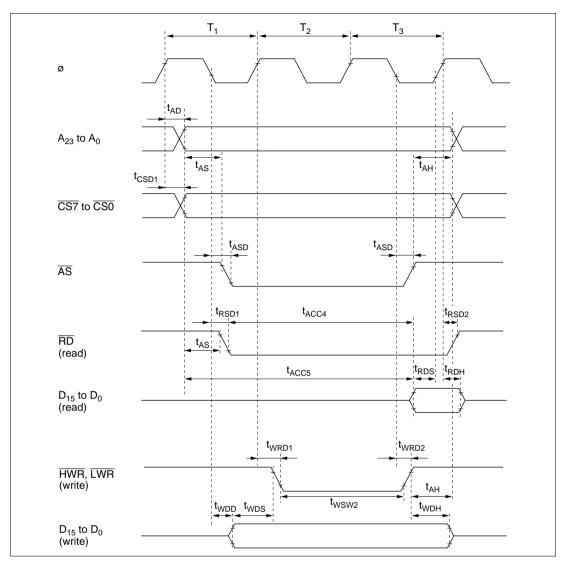


Figure 22-41 Basic Bus Timing (Three-State Access)

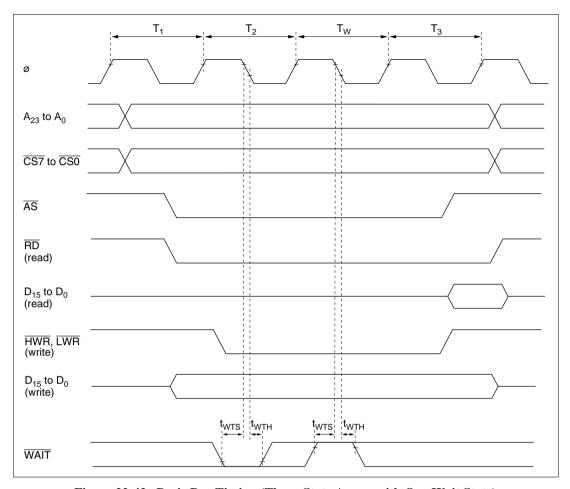


Figure 22-42 Basic Bus Timing (Three-State Access with One Wait State)

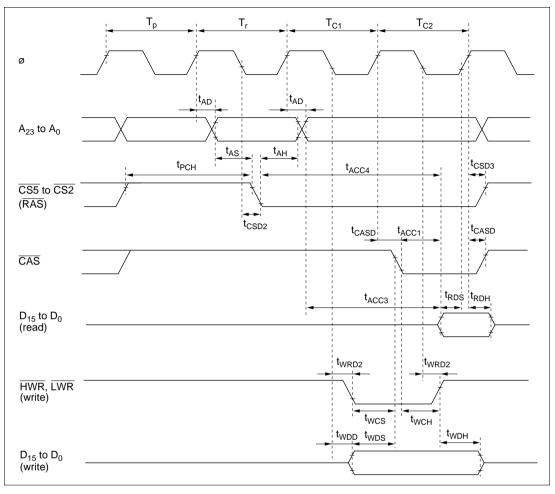


Figure 22-43 DRAM Bus Timing

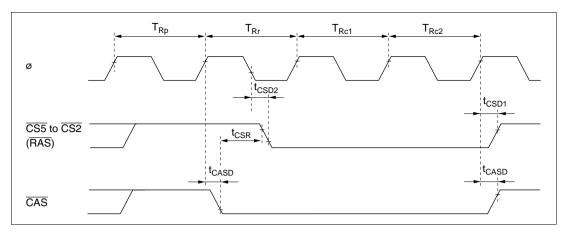


Figure 22-44 CAS-Before-RAS Refresh Timing

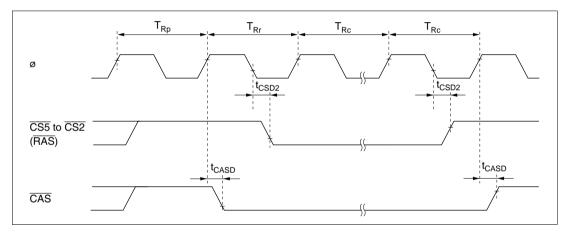


Figure 22-45 Self-Refresh Timing

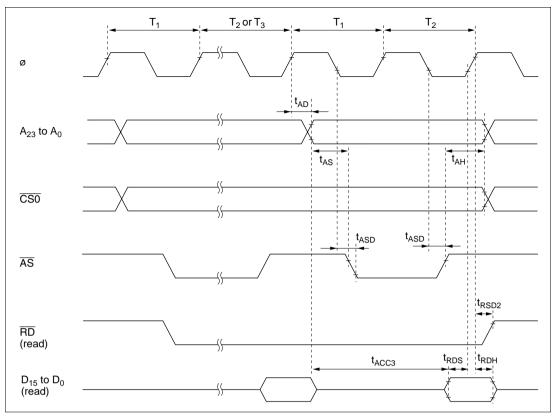


Figure 22-46 Burst ROM Access Timing (Two-State Access)

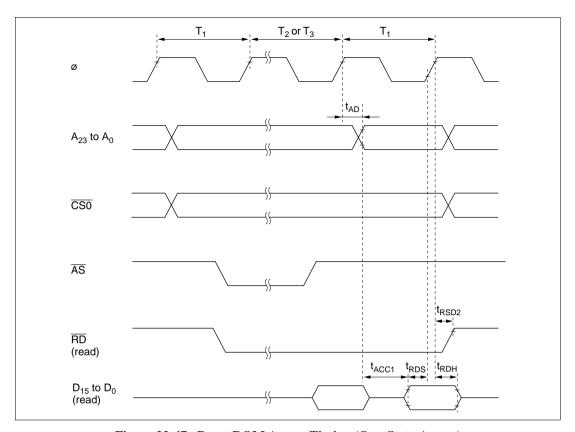


Figure 22-47 Burst ROM Access Timing (One-State Access)

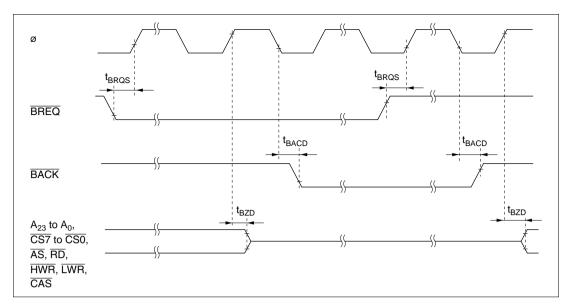


Figure 22-48 External Bus Release Timing

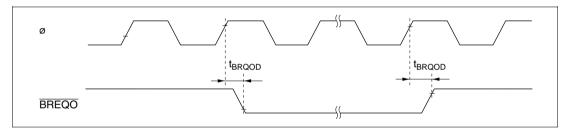


Figure 22-49 External Bus Request Output Timing

(4) DMAC Timing

Table 22-17 lists the DMAC timing.

Table 22-17 DMAC Timing

Condition: V_{CC} = 5.0 V \pm 10%, AV_{CC} = 5.0 V \pm 10%, V_{ref} = 4.5 V to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 10 \text{ to } 20 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

			Condition		Test
Item	Symbol	Min	Max	Unit	Conditions
DREQ setup time	t DRQS	30	_	ns	Figure 22-53
DREQ hold time	t DRQH	10	_		
TEND delay time	t _{TED}	_	20		Figure 22-52
DACK delay time 1	t DACD1	_	20	ns	Figure 22-50,
DACK delay time 2	t DACD2	_	20		Figure 22-51

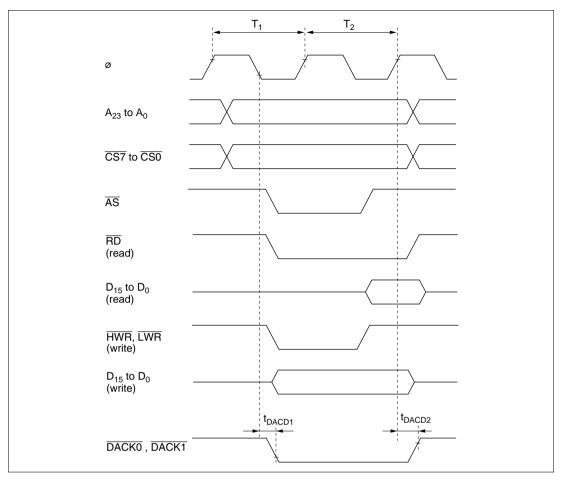


Figure 22-50 DMAC Single Address Transfer Timing (Two-State Access)

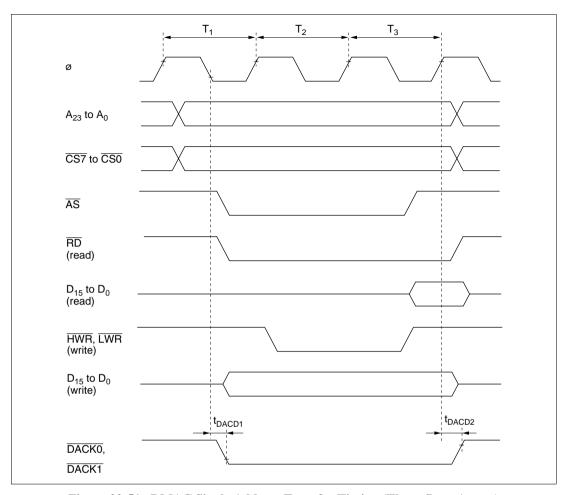


Figure 22-51 DMAC Single Address Transfer Timing (Three-State Access)

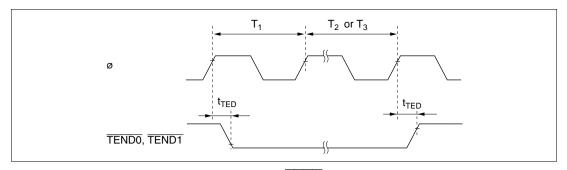


Figure 22-52 DMAC TEND Output Timing

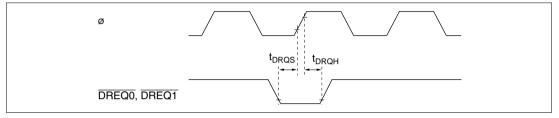


Figure 22-53 DMAC DREQ Intput Timing

(5) Timing of On-Chip Supporting Modules

Table 22-18 lists the timing of on-chip supporting modules.

Table 22-18 Timing of On-Chip Supporting Modules

Condition: V_{CC} = 5.0 V ± 10%, AV_{CC} = 5.0 V ± 10%, V_{ref} = 4.5 V to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 10 \text{ to } 20 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

					Condition		Test
Item			Symbol	Min	Max	Unit	Conditions
PORT	Γ Output data d	lelay time	t _{PWD}	_	50	ns	Figure 22-54
	Input data set	tup time	t _{PRS}	30	_		
	Input data hol	ld time	t _{PRH}	30	_		
PPG	Pulse output	delay time		_	50	ns	Figure 22-55
TPU	Timer output	delay time		_	50	ns	Figure 22-56
	Timer input se	etup time	t TICS	30	_		
	Timer clock in time	nput setup	t _{TCKS}	30	_	ns	Figure 22-57
	Timer clock pulse width	Single edge	t _{TCKWH}	1.5	_	t _{cyc}	
		Both edges	t TCKWL	2.5	_		
TMR	Timer output	delay time	t _{TMOD}	_	50	ns	Figure 22-58
	Timer reset in time	put setup	t _{TMRS}	30	_	ns	Figure 22-60
	Timer clock in time	nput setup	t _{TMCS}	30	_	ns	Figure 22-59
	Timer clock pulse width	Single edge	t _{TMCWH}	1.5	_	t _{cyc}	
		Both edges	t _{TMCWL}	2.5	_		

				(Condition		Test		
Item			Symbol	Min Max		Unit	Conditions		
SCI	Input clock cycle	Asynchro- nous	t _{Scyc}	4	_	t _{cyc}	Figure 22-61		
Input of Inp		Synchro- nous	_	6	_				
	Input clock	oulse width	t _{SCKW}	0.4	0.6	t _{Scyc}			
	Input clock rise time		t _{SCKr}	_	1.5	t _{cyc}			
	Input clock fall time		t _{SCKf}	_	1.5				
	Transmit data delay time		t _{TXD}	_	50	ns	Figure 22-62		
	Receive data setup time (synchronous)		t _{RXS}	50	_	ns			
	Receive data hold time (synchronous)		t _{RXH}	50	_	ns			
con-	Trigger inputime	t setup	t _{TRGS}	30	_	ns	Figure 22-63		

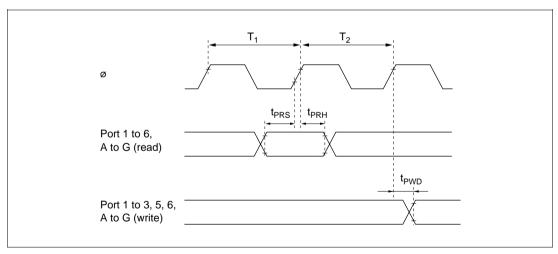


Figure 22-54 I/O Port Input/Output Timing

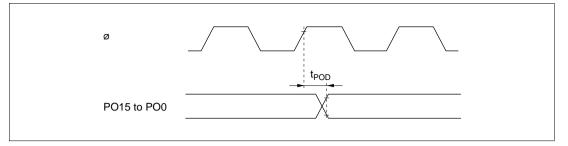


Figure 22-55 PPG Output Timing

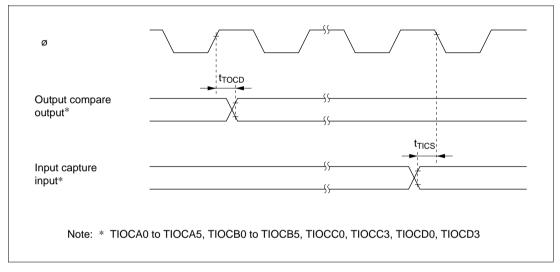


Figure 22-56 TPU Input/Output Timing

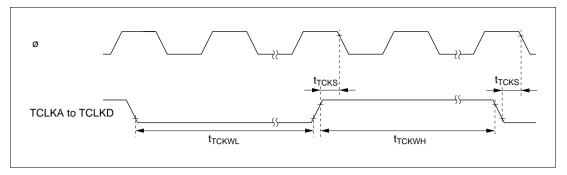


Figure 22-57 TPU Clock Input Timing

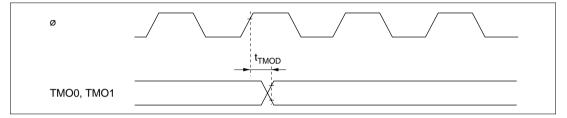


Figure 22-58 8-Bit Timer Output Timing

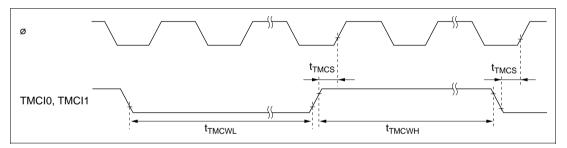


Figure 22-59 8-Bit Timer Clock Input Timing

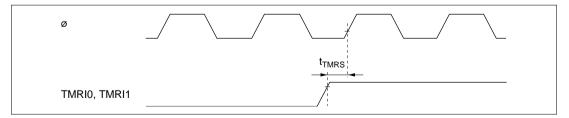


Figure 22-60 8-Bit Timer Reset Input Timing

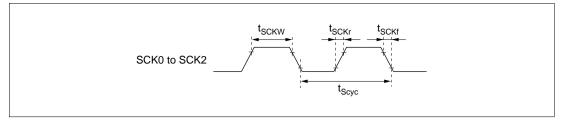


Figure 22-61 SCK Clock Input Timing

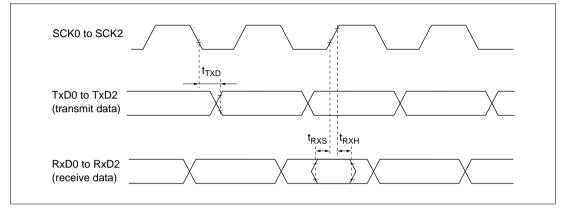


Figure 22-62 SCI Input/Output Timing (Clock Synchronous Mode)

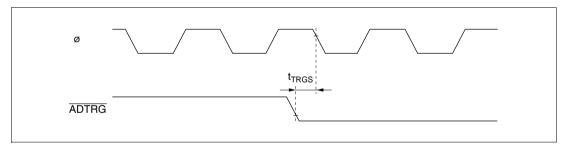


Figure 22-63 A/D Converter External Trigger Input Timing

22.3.4 A/D Conversion Characteristics

Table 22-19 lists the A/D conversion characteristics.

Table 22-19 A/D Conversion Characteristics

Conditions: $V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\phi = 10$ to 20 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

Item	Min	Тур	Max	Unit
Resolution	10	10	10	bits
Conversion time	6.7	_	_	μS
Analog input capacitance	_	_	20	pF
Permissible signal-source impedance	_	_	10* ¹	ΚΩ
	_	_	5* ²	
Nonlinearity error	_	_	±3.5	LSB
Offset error	_	_	±3.5	LSB
Full-scale error	_	_	±3.5	LSB
Quantization error	_	_	±0.5	LSB
Absolute accuracy	_	_	±4.0	LSB

Notes: 1. ϕ 12 MHz

22.3.5 D/A Conversion Characteristics

Table 22-20 lists the D/A conversion characteristics.

Table 22-20 D/A Conversion Characteristics

$$\begin{split} \text{Conditions: } & V_{\text{CC}} = AV_{\text{CC}} = 5.0 \text{ V} \pm 10\%, V_{\text{ref}} = 4.5 \text{ V to } AV_{\text{CC}}, V_{\text{SS}} = AV_{\text{SS}} = 0 \text{ V}, \\ & \varphi = 10 \text{ to } 20 \text{ MHz}, T_{\text{a}} = -20 \text{ to } +75^{\circ}\text{C (regular specifications)}, \\ & T_{\text{a}} = -40 \text{ to } +85^{\circ}\text{C (wide-range specifications)} \end{split}$$

Item	Min	Тур	Max	Unit	Test Conditions		
Resolution	8	8	8	bits			
Conversion time	_	_	10	μS	20-pF capacitive load		
Absolute accuracy	_	±1.0	±1.5	LSB	$2M\Omega$ resistive load		
	_	_	±1.0	LSB	4MΩ resistive load		

Table 22-21 Flash Memory Characteristics

- Preliminary -

Conditions:

$$\begin{split} &V_{CC}=5.0~V\pm10\%,~AV_{CC}=5.0~V\pm10\%,~V_{ref}=4.5~V~to~AV_{CC},~V_{SS}=AV_{SS}=0V\\ &T_a=0~to~+TBD^{\circ}C~(Programming/erasing~operating~temperature,~regular\\ &specifications),~T_a=0~to~+TBD^{\circ}C~(Programming/erasing~operating~temperature,~wide-range~specifications) \end{split}$$

Programming time*1,*2,*4			Symbol Min		Тур	Max	Unit	Te Co	ion		
					TBD	TBD	ms/128 bytes				
Erase time*1,*3,*6		t _E	-	_	TBD	TBD	ms/block				
Reprogramming count		N_{WE}	ic -		_	100	Times				
Programming	Wait time after SWE bit setting*1	Х	,	1	_	_	μs				
	Wait time after PSU bit setting*1	у	;	50	_	_	μs				
	Wait time after P bit setting*1, *4	Z	(z1) -		_	30	μs	1	n	6	;
			(z2) -	_	_	200	μs	7	n	10	000
			(z3) ·		_	10	μs	pr		ar	nal nmi
	Wait time after P bit clear*1	α	;	5	_	_	μs				
	Wait time after PSU bit clear*1	β	;	5	_	_	μs				
	Wait time after PV bit setting*1	γ		4	_	_	μs				
	Wait time after H'FF dummy write*1	ε	;	2	_	_	μs				
	Wait time after PV bit clear*	¹η	:	2	_	_	μs				
	Wait time after SWE bit clear*1	θ	,	100	_	_	μs				
	Maximum programming count*1,*4	N	-	_	_	1000*5	Times				

Item		Symbol	Min	Тур	Max	Unit	Test Condition
Erase	Wait time after SWE bit setting*1	X	1		_	μs	
	Wait time after ESU bit setting*1	у	100	_	_	μs	
	Wait time after E bit setting*1,*6	Z	_	_	10	ms	Erase time wait
	Wait time after E bit clear*1	α	10	_	_	μs	
	Wait time after ESU bit clear*1	β	10	_	_	μs	
	Wait time after EV bit setting*1	γ	20	_	_	μs	
	Wait time after H'FF dummy write*1	/ ε	2	_	_	μs	
	Wait time after EV bit clear*	¹ η	4	_	_	μs	
	Wait time after SWE bit clea	rθ	100	_	_	μs	
	Maximum erase count*1,*6	N	_	_	100	Times	

Notes: 1. Settings of each time must comply with algorithm of writing/erasing.

- Writing time for 128 bytes: indicates the total period in which bit P of flash memory control register 1 (FLMCR1) is set for H8S/2398. Indicates the total period in which bits P1 and P2 of flash memory control registers (FLMCR1, FLMCR2) are set for H8S/2396 and H8S/2395. Writing verification time is not included.
- Erasing time for one block: indicates the period in which bit E of FLMCR1 is set for H8S/2398. Indicates the period in which bits E1 of FLMCR1 and E2 of FLMCR2 are set for H8S/2396 and H8S/2395. Erasing verification time is not included.
- 4. Maximum writing time: $tP(max) = \Sigma$ wait time (z) after setting of bit P
- The maximum writing count (N) must be set to the maximum writing time (tP(max)) or less according the actual set value (z). Wait time (z) must be switched after setting of bit P according to writing count (n).

Writing count n

 $1 \le n \le 6$ $z = 30 \,\mu s$

 $7 \leq n \leq 1000 \hspace{0.5cm} z = 200 \hspace{0.5cm} \mu s$

[In additional writing]

Writing count n

 $1 \le n \le 6$ $z = 10 \,\mu s$

6. Wait time (z) after setting of bit E and the maximum erasing count (N) have the following relationship to the maximum erasing time (tE(max)).

tE(max) = wait time (z) after setting of bit E x maximum erasing count (N)

22.4 Notes on Use

The F-ZTAT and mask-ROM versions satisfy electrical characteristics described in this manual. However, actual electrical characteristics values, operation margins, and noise margins depend on differences in manufacturing processes, on-chip ROM, or layout patterns.

If the system is evaluated using the F-ZTAT version, perform the same evaluation test of the system using the mask-ROM version when switching to the mask-ROM version

22.5 Usage Note (internal voltage step down for the H8S/2398, H8S/2396, and H8S/2395F-ZTAT)

The H8S/2398, H8S/2396, or H8S/2395F-ZTAT have a voltage step down circuit that automatically lowers the power supply voltage, inside the microcomputer, to an adequate level. A capacitor (one 0.47- μF capacitor or two 0.47- μF capacitors connected in parallel) should be connected between the V_{CL} pin (a pin for internal voltage step down circuit) and V_{SS} pin to stabilize the internal voltage. Figure 22-64 shows how to connect the capacitor. Do not connect the V_{CC} power-supply to the V_{CL} pin. Doing so could permanently damage the LSI. (Connect the V_{CC} power-supply to the V_{CC} pin, in the usual way.)

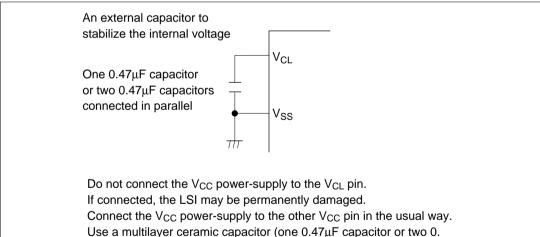


Figure 22-64 V_{CL} Capacitor Connection Method

47μF capacitors connected in parallel) for this circuit, and place it/them

near the V_{CL} pin.

22.6 Electrical Characteristics of H8S/2357 Mask ROM and ZTAT Versions and H8S/2352

22.6.1 Absolute Maximum Ratings

Table 22-22 lists the absolute maximum ratings.

Table 22-22 Absolute Maximum Ratings

— Preliminary —

Item	Symbol	Value	Unit
Power supply voltage	V _{cc}	-0.3 to +7.0	V
Programming voltage*	V_{PP}	-0.3 to +13.5	V
Input voltage (except port 4)	V_{in}	-0.3 to V _{cc} +0.3	V
Input voltage (port 4)	V_{in}	-0.3 to AV _{cc} +0.3	V
Reference voltage	V_{ref}	-0.3 to AV _{cc} +0.3	V
Analog power supply voltage	AV _{cc}	-0.3 to +7.0	V
Analog input voltage	V _{AN}	-0.3 to AV _{cc} +0.3	V
Operating temperature	T _{opr}	Regular specifications: -20 to +75	°C
		Wide-range specifications: -40 to +85	°C
Storage temperature	T _{stg}	-55 to +125	°C

Caution: Permanent damage to the chip may result if absolute maximum rating are exceeded.

Note: * ZTAT version only

22.6.2 DC Characteristics

Table 22-23 lists the DC characteristics. Table 22-13 lists the permissible output currents.

Table 22-23 DC Characteristics (1)

Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}^{*1}$, $T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V _T	1.0	_	_	V	
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	V_T^+	_	_	$V_{\text{CC}} \times 0.7$	V	_
	,	$V_T^+ - V_T^-$	0.4	_	_	V	
Input high voltage	$\overline{\text{RES}}$, $\overline{\text{STBY}}$, NMI, MD ₂ to MD ₀	V_{IH}	$V_{cc} - 0.7$	_	$V_{cc} + 0.3$	V	
	EXTAL	-	$V_{cc} \times 0.7$	_	V _{cc} + 0.3	V	
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃		2.0	_	$V_{cc} + 0.3$ $V_{cc} + 0.3$	V	_
	Port4		2.0	_	$AV_{cc} + 0.3$	V	
Input low voltage	\overline{RES} , \overline{STBY} , MD_2 to MD_0	V_{IL}	-0.3	_	0.5	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃		-0.3	_	0.8	V	
Output high	All output pins	V _{OH}	$V_{cc} - 0.5$	_	_	V	I _{OH} = -200 μA
voltage			3.5	_		V	I _{OH} = -1 mA
Output low	All output pins	V _{oL}	_	_	0.4	V	I _{OL} = 1.6 mA
voltage	Port 1, A to C	-	_	_	1.0	V	I _{OL} = 10 mA
Input leakage	RES		_	_	10.0	μΑ	V _{in} =
current	STBY, NMI, MD ₂ to MD ₀	-	_	_	1.0	μΑ	- 0.5 to V _{cc} – 0.5 V
	Port 4	-	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } AV_{CC} - 0.5 \text{ V}$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } V_{CC} - 0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	50	_	300	μΑ	V _{in} = 0 V
Input	RES	C_{in}	_	_	80	pF	$V_{in} = 0 V$
capacitance	NMI		_	_	50	pF	─_f = 1 MHz T _a = 25°C
	All input pins except RES and NMI		_	_	15	pF	a
Current dissipation*2	Normal operation	I _{CC} *4	_	78 (5.0 V)	122	mA	f = 20 MHz
	Sleep mode	_	_	53 (5.0 V)	84	mA	f = 20 MHz
	Standby mode*3		_	0.01	5.0	μΑ	T _a 50°C
			_	_	20.0		50°C < T _a
Analog power supply current	During A/D and D/A conversion	Al _{cc}	_	0.8 (5.0 V)	2.0	mA	
	Idle	_	_	0.01	5.0	μΑ	_
Reference current	During A/D and D/A conversion	Alcc	_	2.3 (5.0 V)	3.0	mA	_
	Idle		_	0.01	5.0	μΑ	
RAM standby v	oltage	V_{RAM}	2.0	_	_	V	

Notes: 1. If the A/D and D/A converters are not used,do not leave the AV_{CC}, AV_{SS}, and V_{ref} pins open.

Connect ${\rm AV_{cc}}$ and ${\rm V_{ref}}$ to ${\rm V_{cc}},$ and connect ${\rm AV_{ss}}$ to ${\rm V_{ss}}.$

- 2. Current dissipation values are for V_{IH} min = V_{CC} –0.5 V and V_{IL} max = 0.5V with all output pins unloaded and the on-chip pull-up transistors in the off state.
- 3. The values are for V_{RAM} V_{CC} < 4.5V, V_{IH} min = V_{CC} \times 0.9, and V_{IL} max = 0.3 V.
- 4. I_{cc} depends on V_{cc} and f as follows:

 I_{cc} max = 1.0 (mA) + 1.1 (mA/(MHz × V)) × V_{cc} × f [normal mode]

 I_{cc} max = 1.0 (mA) + 0.75 (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-23 DC Characteristics (2)

Conditions: $V_{CC} = 2.7$ to 5.5 V, $AV_{CC} = 2.7$ to 5.5 V, $V_{ref} = 2.7$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V*1, $T_a = -20$ to +75°C (regular specifications), $T_a = -40$ to +85°C (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V _T	$V_{\text{CC}} \times 0.2$	_	_	V	
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	V_T^+	_	_	$V_{CC} \times 0.7$	V	_
voltage	FA ₄ to FA ₇	$V_T^+ - V_T^-$	$V_{cc} \times 0.07$	_	_	V	
Input high voltage	$\overline{\text{RES}}, \overline{\text{STBY}},$ $\overline{\text{NMI}}, \overline{\text{MD}}_2$ $\overline{\text{to MD}}_0$	V _{IH}	$V_{cc} \times 0.9$	_	V _{cc} +0.3	V	
	EXTAL	-	$V_{\rm CC} \times 0.7$	_	V _{cc} +0.3	V	_
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃	-	$V_{cc} \times 0.7$	_	V _{cc} +0.3	V	_
	Port 4	=	$V_{\text{CC}} \times 0.7$	_	AV _{cc} +0.3	V	_
Input low voltage	RES, STBY, MD ₂ to MD ₀	V _{IL}	-0.3	_	$V_{cc} \times 0.1$	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ ,	-	-0.3	_	$V_{cc} \times 0.2$	V	V _{CC} < 4.0 V
	PA ₀ to PA ₃				8.0		$V_{\rm CC}$ = 4.0 to 5.5 V
Output high	All output pins	V _{OH}	V _{cc} - 0.5	_	_	V	I _{OH} = -200 μA
voltage			V _{cc} – 1.0	_	_	V	$I_{OH} = -1 \text{ mA}$
Output low	All output pins	V_{OL}	_	_	0.4	V	I _{OL} = 1.6 mA
voltage	Port 1, A to C	-	_	_	1.0	V	V_{CC} 4 V $I_{OL} = 5 \text{ mA}$ $4.0 < V_{CC}$ 5.5 V $I_{OL} = 10 \text{ mA}$
Input leakage	RES	I _{in}	_	_	10.0	μΑ	V _{in} =
current	STBY, NMI, MD ₂ to MD ₀	-	_		1.0	μΑ	$0.5 \text{ to V}_{cc} - 0.5 \text{V}$
	Port 4	-	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } AV_{CC} - 0.5V$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} =$ 0.5 to $V_{CC} - 0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	10	_	300	μΑ	$V_{CC} = 2.7 \text{ V to}$ 5.5 V, $V_{in} = 0 \text{ V}$
Input	RES	C_{in}		_	80	pF	$V_{in} = 0 V$
capacitance	NMI		_	_	50	pF	f = 1 MHz Ta = 25°C
	All input pins except RES and NMI		_	_	15	pF	
Current dissipation*2	Normal operation	I _{CC} *4	_	23 (3.0 V)	62)	mA	f = 10 MHz
	Sleep mode		_	16 (3.0 V)	42	mA	f = 10 MHz
	Standby	=	_	0.01	5.0	μΑ	T _a 50°C
	mode*3		_	_	20.0		50°C < T _a
Analog power supply current	During A/D and D/A conversion	Al _{cc}	_	0.2 (3.0 V)	2.0	mA	
	Idle		_	0.01	5.0	μΑ	
Reference current	During A/D and D/A conversion	Al _{cc}		1.4 (3.0 V)	3.0	mA	
	Idle		_	0.01	5.0	μΑ	
RAM standby v	RAM standby voltage		2.0			V	

Notes: 1. If the A/D and D/A converters are not used, do not leave the AV_{cc} , AV_{ss} , and V_{ref} pins open.

Connect AV_{CC} and V_{ref} to V_{CC} , and connect AV_{SS} to V_{SS} .

- 2. Current dissipation values are for V_{IH} min = V_{CC} –0.5 V and V_{IL} max = 0.5V with all output pins unloaded and the on-chip pull-up transistors in the off state.
- 3. The values are for V_{RAM} V_{CC} < 2.7 V, V_{IH} min = V_{CC} \times 0.9, and V_{IL} max = 0.3 V.
- 4. I cc depends on Vcc and f as follows:

 I_{cc} max = 1.0 (mA) + 1.1 (mA/(MHz × V)) × V_{cc} × f [normal mode]

 I_{cc} max = 1.0 (mA) + 0.75 (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-23 DC Characteristics (3)

Conditions: $V_{CC} = 3.0$ to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V*1, $T_a = -20$ to +75°C (regular specifications), $T_a = -40$ to +85°C (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V _T	$V_{\text{CC}} \times 0.2$	_	_	V	
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	V_T^+	_	_	$V_{cc} \times 0.7$	V	
voltage	FA ₄ to FA ₇	$V_T^+ - V_T^-$	$V_{CC} \times 0.07$	_	_	V	
Input high voltage	$\overline{\text{RES}}, \overline{\text{STBY}},$ $\overline{\text{NMI}}, \overline{\text{MD}}_2$ $\overline{\text{to MD}}_0$	V _{IH}	$V_{cc} \times 0.9$	_	V _{cc} +0.3	V	
	EXTAL	-	$V_{CC} \times 0.7$	_	V _{cc} +0.3	V	_
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃	-	$V_{cc} \times 0.7$	_	V _{cc} +0.3	V	_
	Port 4	=	$V_{CC} \times 0.7$	_	AV _{cc} +0.3	V	_
Input low voltage	$\overline{\text{RES}}$, $\overline{\text{STBY}}$, $\overline{\text{MD}}_2$ to $\overline{\text{MD}}_0$	V _{IL}	-0.3	_	$V_{CC} \times 0.1$	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ ,	-	-0.3	_	$V_{cc} \times 0.2$	V	V _{cc} < 4.0 V
	PA ₀ to PA ₃				0.8		$V_{CC} = 4.0 \text{ to } 5.5 \text{ V}$
Output high	All output pins	V _{OH}	V _{cc} - 0.5	_	_	V	I _{OH} = -200 μA
voltage			V _{CC} - 1.0	_	_	V	$I_{OH} = -1 \text{ mA}$
Output low	All output pins	V_{OL}	_	_	0.4	V	I _{OL} = 1.6 mA
voltage	Port 1, A to C	-	_	_	1.0	V	V_{CC} 4 V $I_{OL} = 5 \text{ mA}$ $4.0 < V_{CC}$ 5.5 V $I_{OL} = 10 \text{ mA}$
Input leakage	RES	I _{in}	_	_	10.0	μΑ	V _{in} =
current	STBY, NMI, MD ₂ to MD ₀	-	_		1.0	μΑ	- 0.5 to V _{cc} – 0.5V
	Port 4	-	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } AV_{CC} - 0.5V$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} =$ 0.5 to $V_{CC} -0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	10	_	300	μΑ	$V_{CC} = 3.0 \text{ V to}$ 5.5 V, $V_{in} = 0 \text{ V}$
Input	RES	C_{in}		_	80	pF	$V_{in} = 0 V$
capacitance	NMI		_	_	50	pF	f = 1 MHz _Ta = 25°C
	All input pins except RES and NMI		_	_	15	pF	
Current dissipation*2	Normal operation	I _{CC} *4	_	32 (3.3 V)	80	mA	f = 13 MHz
	Sleep mode		_	22 (3.3 V)	55	mA	f = 13 MHz
	Standby	_	_	0.01	5.0	μΑ	T _a 50°C
	mode*3		_	_	20		50°C < T _a
Analog power supply current	During A/D and D/A conversion	Al _{cc}	_	0.3 (3.3 V)	2.0	mA	
	Idle		_	0.01	5.0	μΑ	
Reference current	During A/D and D/A conversion	Al _{cc}		1.6 (3.3 V)	3.0	mA	
	Idle		_	0.01	5.0	μΑ	
RAM standby v	oltage	V_{RAM}	2.0			V	

Notes: 1. If the A/D and D/A converters are not used, do not leave the ${\rm AV_{cc}}$, ${\rm AV_{ss}}$, and ${\rm V_{ref}}$ pins open.

Connect AV_{CC} and V_{ref} to V_{CC} , and connect AV_{SS} to V_{SS} .

- 2. Current dissipation values are for V_{IH} min = V_{CC} –0.5 V and V_{IL} max = 0.5V with all output pins unloaded and the on-chip pull-up transistors in the off state.
- 3. The values are for V_{RAM} V_{CC} < 3.0 V, V_{IH} min = V_{CC} \times 0.9, and V_{IL} max = 0.3 V.
- 4. I cc depends on Vcc and f as follows:

 I_{cc} max = 1.0 (mA) + 1.1 (mA/(MHz × V)) × V_{cc} × f [normal mode]

 I_{cc} max = 1.0 (mA) + 0.75 (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-24 Permissible Output Currents

Conditions: $V_{CC} = 2.7$ to 5.5 V, $AV_{CC} = 2.7$ to 5.5 V, $V_{ref} = 2.7$ to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit
Permissible output	Port 1, A to C	I _{OL}	_	_	10	mA
low current (per pin)	Other output pins		_	_	2.0	mA
Permissible output low current (total)	Total of 32 pins including port 1 and A to C	ΣΙ _{OL}	_	_	80	mA
	Total of all output pins, including the above	_	_	_	120	mA
Permissible output high current (per pin)	All output pins	- I _{OH}	_	_	2.0	mA
Permissible output high current (total)	Total of all output pins	Σ –I _{OH}	_	_	40	mA

Notes: 1. To protect chip reliability, do not exceed the output current values in table 22-24.

2. When driving a darlington pair or LED directly, always insert a current-limiting resistor in the output line, as show in figures 22-65 and 22-66.

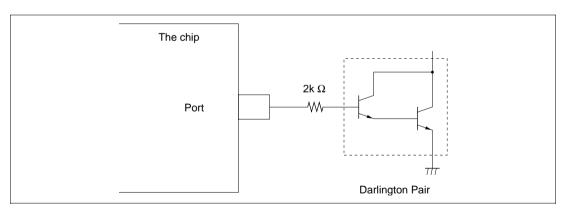


Figure 22-65 Darlington Pair Drive Circuit (Example)

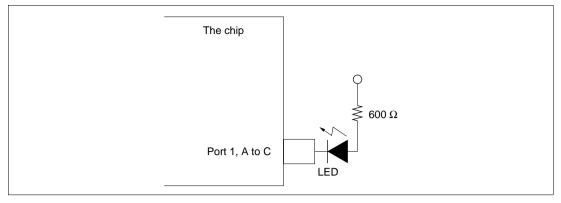


Figure 22-66 LED Drive Circuit (Example)

22.6.3 AC Characteristics

Figure 22-67 show, the test conditions for the AC characteristics.

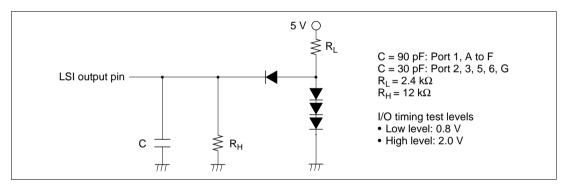


Figure 22-67 Output Load Circuit

(1) Clock Timing

Table 22-25 lists the clock timing

Table 22-25 Clock Timing

Condition A: $V_{CC} = 2.7 \text{ to } 5.5 \text{ V}, AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}, V_{ref} = 2.7 \text{ V to } AV_{CC}$ $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 2 \text{ to } 10 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition B: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 2 \text{ to } 20 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition C: $V_{CC} = 3.0 \text{ to } 5.5 \text{ V}, AV_{CC} = 3.0 \text{ to } 5.5 \text{ V}, V_{ref} = 3.0 \text{ V to } AV_{CC}$ $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 2 \text{ to } 13 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

		Cond	dition A	Test					
Item	Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions
Clock cycle time	t _{cyc}	100	500	50	500	76	500	ns	Figure 22-68
Clock high pulse width	t _{CH}	35	_	20	_	23	_	ns	_
Clock low pulse width	t _{CL}	35	_	20	_	23	_	ns	_
Clock rise time	t _{Cr}	_	15	_	5	_	15	ns	_
Clock fall time	t _{Cf}	_	15	_	5	_	15	ns	_
Clock oscillator setting time at reset (crystal)	t _{OSC1}	20	_	10	_	20	_	ms	Figure 22-69
Clock oscillator setting time in software standby (crystal)	t _{OSC2}	20	_	10	_	20	_	ms	Figure 21-2
External clock output stabilization delay time	t _{DEXT}	500	_	500	_	500	_	μs	Figure 22-69

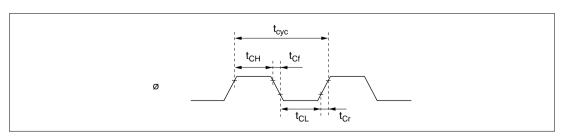


Figure 22-68 System Clock Timing

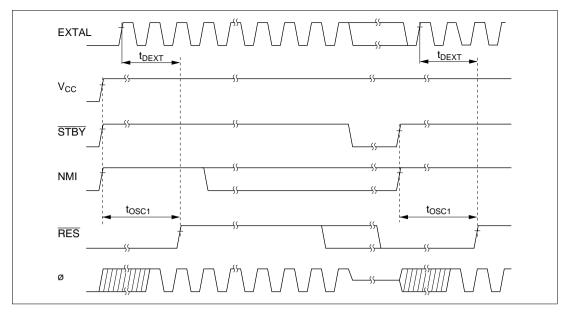


Figure 22-69 Oscillator Settling Timing

(2) Control Signal Timing

Table 22-26 lists the control signal timing.

Table 22-26 Control Signal Timing

Condition A:
$$V_{CC} = 2.7$$
 to 5.5 V, $AV_{CC} = 2.7$ to 5.5 V, $V_{ref} = 2.7$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 2$ to 10 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

Condition B:
$$V_{CC} = 5.0 \text{ V} \pm 10\%$$
, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition C:
$$V_{CC} = 3.0$$
 to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 2$ to 13 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

		Cond	dition A		Test				
Item	Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions
RES setup time	t _{RESS}	200	_	200	_	200	_	ns	Figure 22-70
RES pulse width	t _{RESW}	20		20	_	20	_	$t_{ m cyc}$	
NMI reset setup time*	t _{NMIRS}	250	_	200	_	250	_	ns	
NMI reset hold time*	t _{NMIRH}	200	_	200	_	200	_		_
NMI setup time	t _{NMIS}	250		150	_	250	_	ns	Figure 22-71
NMI hold time	t _{NMIH}	10	_	10	_	10	_		
NMI pulse width (exiting software standby mode)	t _{NMIW}	200	_	200	_	200	_	ns	
IRQ setup time	t IRQS	250	_	150	_	250	_	ns	_
IRQ hold time	t _{IRQH}	10	_	10	_	10	_	ns	_
IRQ pulse width (exiting software standby mode)	t _{IRQW}	200	_	200	_	200	_	ns	

Note: * Applies to the ZTAT version only.

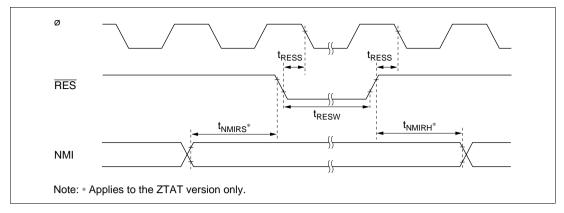


Figure 22-70 Reset Input Timing

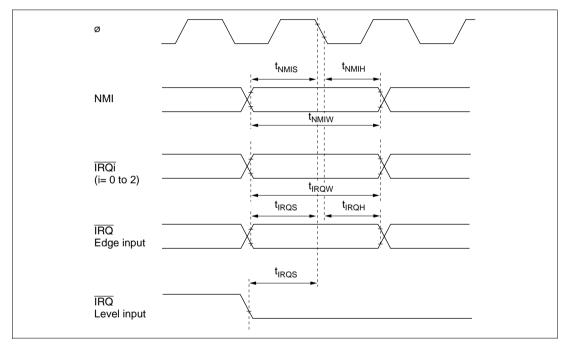


Figure 22-71 Interrupt Input Timing

(3) Bus Timing

Table 22-27 lists the bus timing.

Table 22-27 Bus Timing

Condition A: $V_{CC} = 2.7 \text{ to } 5.5 \text{ V}, AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}, V_{ref} = 2.7 \text{ V} \text{ to } AV_{CC},$

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 2 \text{ to } 10 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C} \text{ (regular specifications)},$

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition B: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 2 \text{ to } 20 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C} \text{ (regular specifications)},$

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition C: $V_{CC} = 3.0 \text{ to } 5.5 \text{ V}, AV_{CC} = 3.0 \text{ to } 5.5 \text{ V}, V_{ref} = 3.0 \text{ V to } AV_{CC},$

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 2 \text{ to } 13 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

		Cond	lition A	Condition B		Condition C			Test
Item	Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions
Address delay time	t _{AD}	_	40	_	20	_	40	ns	Figure 22-72 to
Address setup time	t _{AS}	0.5 × t _{cyc} - 30	_	0.5 × t _{cyc} – 15	_	0.5 × t _{cyc} - 30	_	ns	Figure 22-79
Address hold time	t _{AH}	$0.5 \times t_{cyc} - 20$	_	$0.5 \times t_{cyc} - 10$	_	$0.5 \times t_{cyc} - 20$	_	ns	-
Precharge time	t _{PCH}	$1.5 \times t_{cyc} - 40$	_	$1.5 \times t_{cyc} - 20$	_	$1.5 \times t_{\text{cyc}} - 40$	_	ns	=
CS delay time 1	t _{CSD1}		40		20		40	ns	=
CS delay time 2	t _{CSD2}		40		20	_	40	ns	=
CS delay time 3	t _{CSD3}	_	40	_	25	_	40	ns	_
AS delay time	t ASD	_	40	_	20	_	40	ns	_
RD delay time 1	t _{RSD1}	_	40	_	20	_	40	ns	_
RD delay time 2	t _{RSD2}	_	40	_	20	_	40	ns	_
CAS delay time	t CASD	_	40	_	20	_	40	ns	_
Read data setup time	t _{RDS}	30	_	15	_	30	_	ns	_
Read data hold time	t _{RDH}	0	_	0	_	0	_	ns	_
Read data access time1	t _{ACC1}	_	$1.0 \times t_{cyc} - 50$	_	$1.0 \times t_{cyc} - 25$	_	$1.0 \times t_{cyc} - 50$	ns	
Read data access time2	t _{ACC2}	_	1.5 × t _{cyc} – 50	_	1.5 × t _{cyc} – 25	_	1.5 × t _{cyc} – 50	ns	_
Read data access time3	t _{ACC3}	_	2.0 × t _{cyc} – 50	_	2.0 × t _{cyc} – 25	_	2.0 × t _{cyc} – 50	ns	_

		Cond	ition A	Condition B		Cond	ition C	_	Test	
Item	Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions	
Read data access time 4	t _{ACC4}	_	2.5 × t _{cyc} – 50	_	2.5 × t _{cyc} – 25	_	2.5 × t _{cyc} – 50	ns	Figure 22-72 to Figure 22-79	
Read data access time 5	t _{ACC5}	_	$3.0 \times t_{cyc} - 50$	_	$3.0 \times t_{cyc} - 25$	_	$3.0 \times t_{\rm cyc} - 50$	ns	_	
WR delay time 1	t _{WRD1}	_	40	_	20	_	40	ns	_	
WR delay time 2	t _{WRD2}	_	40	_	20	_	40	ns	_	
WR pulse width 1	t _{WSW1}	$1.0 \times t_{cyc} - 40$	_	$1.0 \times t_{cyc} - 20$	_	$1.0 \times t_{cyc} - 40$	_	ns		
WR pulse width 2	t _{WSW2}	1.5 × t _{cyc} - 40	_	1.5 × t _{cyc} – 20	_	1.5 × t _{cyc} - 40	_	ns	-	
Write data delay time	t _{WDD}	_	60	_	30	_	60	ns	_	
Write data setup time	t _{WDS}	$0.5 \times t_{cyc} - 40$	_	0.5 × t _{cyc} – 20	_	$0.5 \times t_{cyc} - 33$	_	ns		
Write data hold time	t _{WDH}	0.5 × t _{cyc} – 20	_	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} – 20	_	ns	_	
WR setup time	twcs	$0.5 \times t_{cyc} - 20$	_	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} - 20	_	ns	-	
WR hold time	t _{WCH}	0.5 × t _{cyc} – 20	_	$0.5 \times t_{cyc} - 10$	_	0.5 × t _{cyc} – 20	_	ns	-	
CAS setup time	t _{CSR}	$0.5 \times t_{cyc} - 20$	_	$0.5 \times t_{cyc} - 10$	_	$0.5 \times t_{\rm cyc} - 20$	_	ns	Figure 22-76	
WAIT setup time	twrs	60	_	30	_	60	_	ns	Figure 22-74	
WAIT hold time	t _{wth}	10	_	5	_	10	_	ns		
BREQ setup time	t BRQS	60	_	30	_	60	_	ns	Figure 22-80	
BACK delay time	t BACD	_	30	_	15	_	30	ns	_	
Bus-floating time	t _{BZD}	_	100	_	50	_	100	ns		
BREQO delay time	t BRQOD	_	60	_	30	_	60	ns	Figure 22-81	

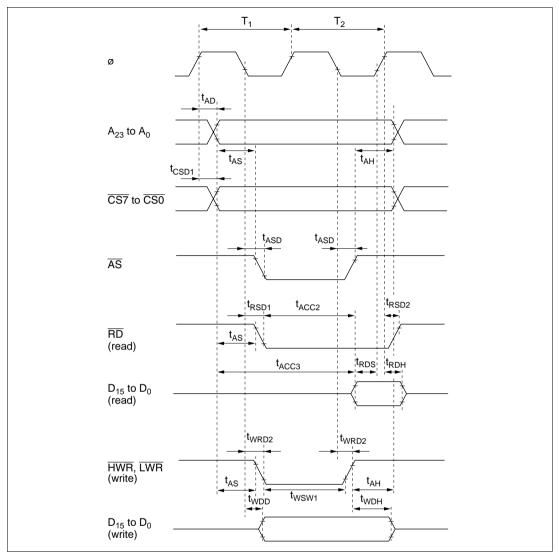


Figure 22-72 Basic Bus Timing (Two-State Access)

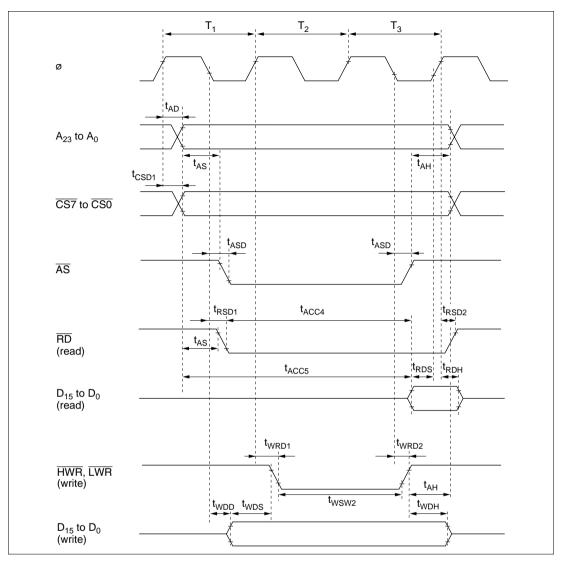


Figure 22-73 Basic Bus Timing (Three-State Access)

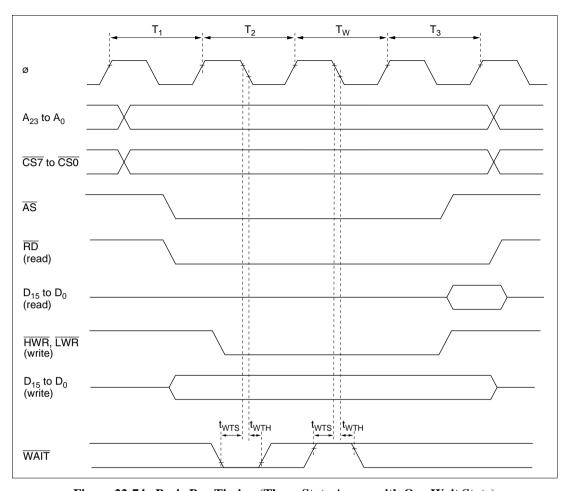


Figure 22-74 Basic Bus Timing (Three-State Access with One Wait State)

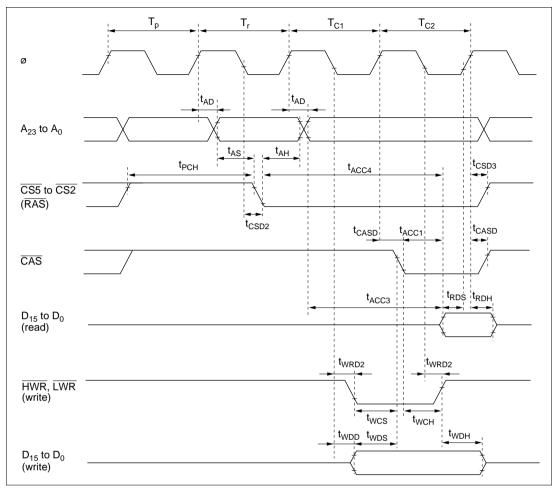


Figure 22-75 DRAM Bus Timing

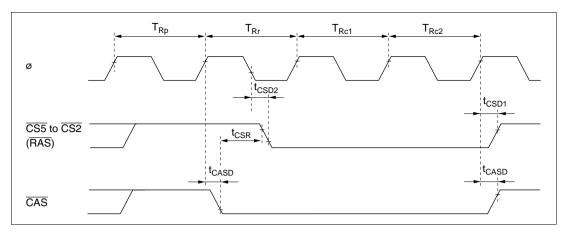


Figure 22-76 CAS-Before-RAS Refresh Timing

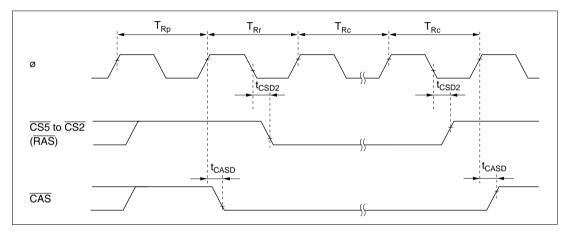


Figure 22-77 Self-Refresh Timing

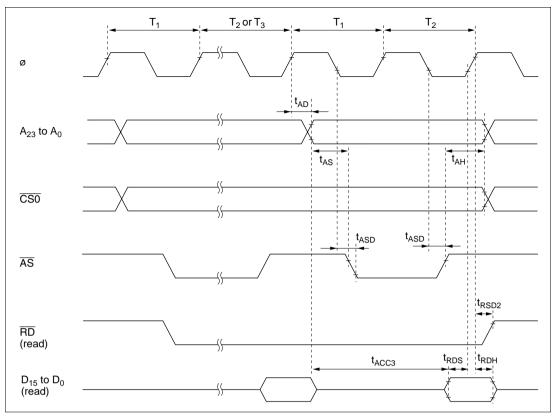


Figure 22-78 Burst ROM Access Timing (Two-State Access)

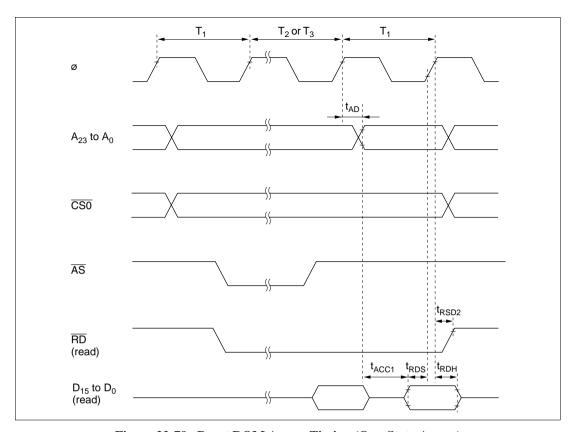


Figure 22-79 Burst ROM Access Timing (One-State Access)

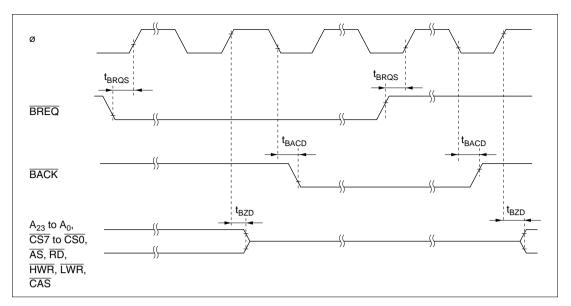


Figure 22-80 External Bus Release Timing

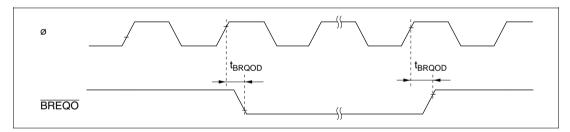


Figure 22-81 External Bus Request Output Timing

(4) DMAC Timing

Table 22-28 lists the DMAC timing.

Table 22-28 DMAC Timing

Condition A:
$$V_{CC} = 2.7 \text{ V}$$
 to 5.5 V, $AV_{CC} = 2.7 \text{ V}$ to 5.5 V, $V_{ref} = 2.7 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0V$, $\emptyset = 2$ to 10 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition B:
$$V_{CC} = 5.0 \text{ V} \pm 10\%$$
, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

$$\begin{array}{ll} \mbox{Condition C:} & V_{CC} = 3.0 \mbox{ to } 5.5 \mbox{ V, } AV_{CC} = 3.0 \mbox{ to } 5.5 \mbox{ V, } V_{ref} = 3.0 \mbox{ V to } AV_{CC}, \\ & V_{SS} = AV_{SS} = 0 \mbox{ V, } \emptyset = 2 \mbox{ to } 13 \mbox{ MHz, } T_a = -20 \mbox{ to } +75^{\circ}\mbox{C (regular specifications)}, \\ & T_a = -40 \mbox{ to } +85^{\circ}\mbox{C (wide-range specifications)} \\ \end{array}$$

		Condition A		Condition B		Condition C			Test	
Item	Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions	
DREQ setup time	t DRQS	40	_	30	_	40	_	ns	Figure 22-85	
DREQ hold time	t DRQH	10	_	10	_	10	_			
TEND delay time	t _{TED}	_	40	_	20	_	40	- "	Figure 22-84	
DACK delay time 1	t DACD1	_	40	_	20	_	40	ns	Figure 22-82,	
DACK delay time 2	t DACD2	_	40	_	20	_	40		Figure 22-83	

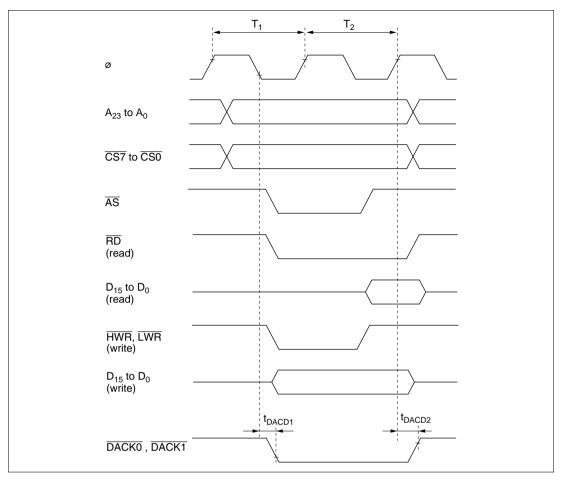


Figure 22-82 DMAC Single Address Transfer Timing (Two-State Access)

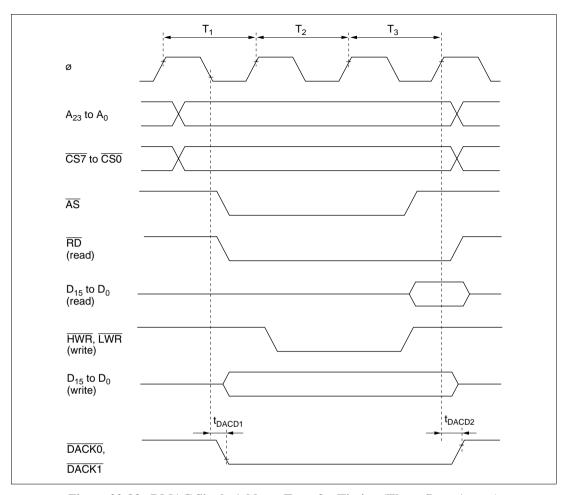


Figure 22-83 DMAC Single Address Transfer Timing (Three-State Access)

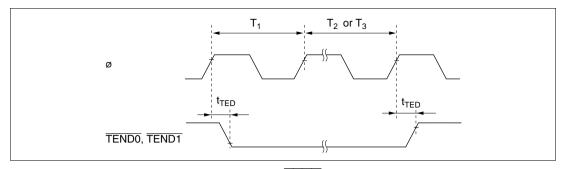


Figure 22-84 DMAC TEND Output Timing

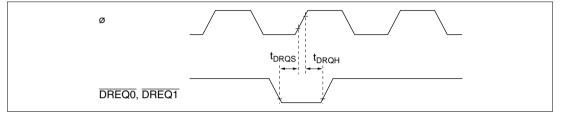


Figure 22-85 DMAC DREQ Intput Timing

(5) Timing of On-Chip Supporting Modules

Table 22-29 lists the timing of on-chip supporting modules.

Table 22-29 Timing of On-Chip Supporting Modules

Condition A:
$$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$$
, $AV_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$, $V_{ref} = 2.7 \text{ V to } AV_{CC}$, $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2 \text{ to } 10 \text{ MHz}$, $T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition B:
$$V_{CC} = 5.0 \text{ V} \pm 10\%$$
, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition C:
$$V_{CC} = 3.0$$
 to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 2$ to 13 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

				Cond	dition A	2	Test				
Item			Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions
PORT	Output data delay time		t _{PWD}	_	100	_	50	_	75	ns	Figure 22-86
	Input data set	up time	t _{PRS}	50	_	30	_	50	_		
	Input data hol	d time	t _{PRH}	50	_	30	_	50	_		
PPG	Pulse output of	delay time	t _{POD}	_	100	_	50	_	75	ns	Figure 22-87
TPU	Timer output	delay time	t _{TOCD}	_	100	_	50	_	75	ns	Figure 22-88
	Timer input setup time		t _{TICS}	50	_	30	_	50	_		
	Timer clock input setup time		t _{TCKS}	50	_	30	_	50	_	ns	Figure 22-89
	Timer clock pulse width	Single edge	t _{TCKWH}	1.5	_	1.5	_	1.5	_	t _{cyc}	_
		Both edges	t TCKWL	2.5	_	2.5	_	2.5	_	_	
TMR	Timer output	delay time	t _{TMOD}	_	100	_	50	_	75	ns	Figure 22-90
	Timer reset in time	put setup	t _{TMRS}	50	_	30	_	50	_	ns	Figure 22-92
	Timer clock input setup time		t _{TMCS}	50	_	30	_	50	_	ns	Figure 22-91
	Timer clock pulse width	Single edge	t _{TMCWH}	1.5		1.5		1.5	_	t _{cyc}	_
		Both edges	t _{TMCWL}	2.5	_	2.5	_	2.5	_		

	Condition A Condition B Condition C							C	Test		
Item			Symbol	Min	Max	Min	Max	Min	Max	Unit	Conditions
WDT	Overflow ou time	tput delay	t _{WOVD}	_	100	_	50	_	75	ns	Figure 22-93
SCI	Input clock cycle	Asynchro- nous	t _{Scyc}	4	_	4	_	4	_	t _{cyc}	Figure 22-94
		Synchro- nous		6	_	6	_	6	_	_	
	Input clock pulse width		t _{SCKW}	0.4	0.6	0.4	0.6	0.4	0.6	t _{Scyc}	
	Input clock rise time		t _{SCKr}	_	1.5	_	1.5	_	1.5	t cyc	_
	Input clock fall time		t _{SCKf}	_	1.5	_	1.5	_	1.5		
	Transmit data delay time		t _{TXD}	_	100	_	50	_	75	ns	Figure 22-95
	Receive data setup time (synchronous)		t _{RXS}	100	_	50	_	75	_	ns	_
	Receive data hold time (synchronous)		t _{RXH}	100	_	50	_	75	_	ns	_
A/D con- verter	Trigger inputime	t setup	t _{TRGS}	50	_	30	_	50	_	ns	Figure 22-96

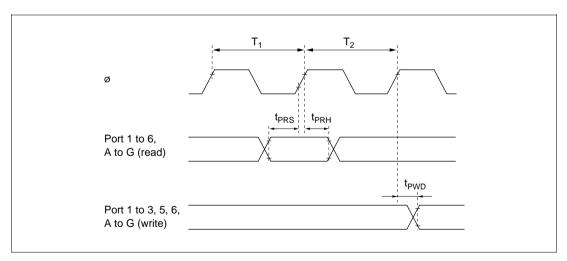


Figure 22-86 I/O Port Input/Output Timing

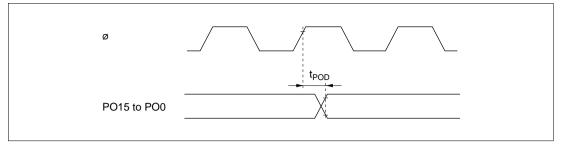


Figure 22-87 PPG Output Timing

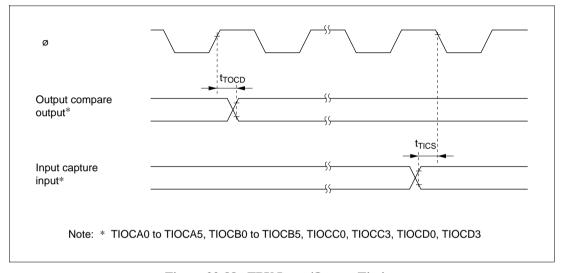


Figure 22-88 TPU Input/Output Timing

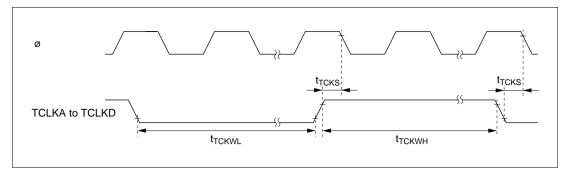


Figure 22-89 TPU Clock Input Timing

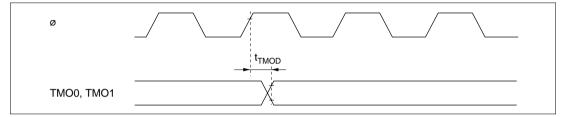


Figure 22-90 8-Bit Timer Output Timing

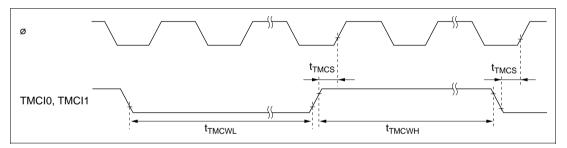


Figure 22-91 8-Bit Timer Clock Input Timing

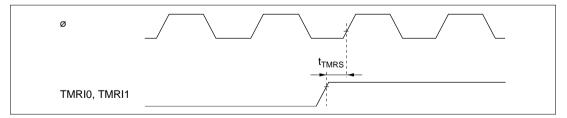


Figure 22-92 8-Bit Timer Reset Input Timing

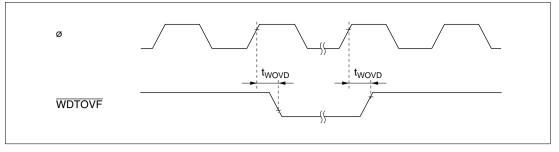


Figure 22-93 WDT Output Timing

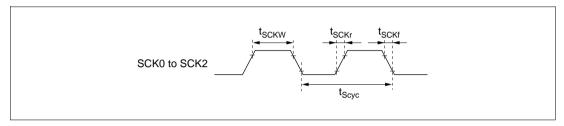


Figure 22-94 SCK Clock Input Timing

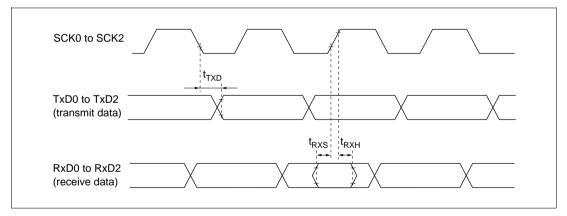


Figure 22-95 SCI Input/Output Timing (Clock Synchronous Mode)

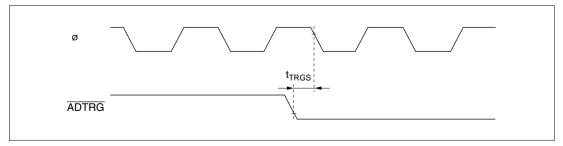


Figure 22-96 A/D Converter External Trigger Input Timing

22.6.4 A/D Conversion Characteristics

Table 22-30 lists the A/D conversion characteristics.

Table 22-30 A/D Conversion Characteristics

Condition A:
$$V_{CC} = AV_{CC} = 2.7 \text{ V to } 5.5 \text{ V}, V_{ref} = 2.7 \text{ V to } AV_{CC}, V_{SS} = AV_{SS} = 0 \text{ V},$$

 $\emptyset = 2 \text{ to } 10 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C} \text{ (regular specifications)},$
 $T_a = -40 \text{ to } +85^{\circ}\text{C} \text{ (wide-range specifications)}$

Condition B:
$$V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$$
, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition C:
$$V_{CC} = AV_{CC} = 3.0$$
 to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 2$ to 13 MHz, $T_a = -20$ to +75°C (regular specifications), $T_a = -40$ to +85°C (wide-range specifications)

	Condition A			С	onditio	on B	С			
Item	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Resolution	10	10	10	10	10	10	10	10	10	bits
Conversion time	13.4	_	_	6.7	_	_	10.4	_	_	μs
Analog input capacitance	_	_	20	_	_	20	_	_	20	pF
Permissible signal-source	_	_	10* ¹	_	_	10* ³	_	_	10* ¹	k
impedance	_	_	5* ²	_	_	5*4	_	_	5* ⁵	
Nonlinearity error	_	_	±7.5	_	_	±3.5	_	_	±7.5	LSB
Offset error	_	_	±7.5	_	_	±3.5	_	_	±7.5	LSB
Full-scale error	_	_	±7.5	_	_	±3.5	_	_	±7.5	LSB
Quantization	_	_	±0.5	_	_	±0.5	_	_	±0.5	LSB
Absolute accuracy	_	_	±8.0	_	_	±4.0	_	_	±8.0	LSB

Notes: 1. 4.0 V AV _{cc} 5.5 V

2. 2.7 V AV $_{\text{CC}} < 4.0 \text{ V}$

3. ø 12 MHz

4. ø > 12 MHz

5. 3.0 V AV $_{CC} < 4.0 \text{ V}$

22.6.5 D/A Conversion Characteristics

Table 22-31 lists the D/A conversion characteristics

Table 22-31 D/A Conversion Characteristics

Condition A:
$$V_{CC} = AV_{CC} = 2.7 \text{ V to } 5.5 \text{ V}, V_{ref} = 2.7 \text{ V to } AV_{CC}, V_{SS} = AV_{SS} = 0 \text{ V},$$

 $\emptyset = 2 \text{ to } 10 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C} \text{ (regular specifications)},$
 $T_a = -40 \text{ to } +85^{\circ}\text{C} \text{ (wide-range specifications)}$

Condition B:
$$V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$$
, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

$$\begin{split} \text{Condition C:} \quad & V_{\text{CC}} = \text{AV}_{\text{CC}} = 3.0 \text{ to } 5.5 \text{ V}, V_{\text{ref}} = 3.0 \text{ V to } \text{AV}_{\text{CC}}, V_{\text{SS}} = \text{AV}_{\text{SS}} = 0 \text{ V}, \\ & \emptyset = 2 \text{ to } 13 \text{ MHz}, T_{\text{a}} = -20 \text{ to } +75^{\circ}\text{C (regular specifications)}, \\ & T_{\text{a}} = -40 \text{ to } +85^{\circ}\text{C (wide-range specifications)} \end{split}$$

	Co	onditio	on A	Co	nditio	on B	Co	onditio	on C		
Item	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Resolution	8	8	8	8	8	8	8	8	8	bit	
Conversion time	_	_	10	_	_	10	_	_	10	μs	20-pF capacitive load
Absolute accuracy	_	±2.0	±3.0	_	±1.0	±1.5	_	±2.0	±3.0	LSB	2-M resistive load
	_	_	±2.0	_	_	±1.0	_	_	±2.0	LSB	4-M resistive load

22.7 Electrical Characteristics of H8S/2357 F-ZTAT Version

22.7.1 Absolute Maximum Ratings

Table 22-32 lists the absolute maximum ratings.

Table 22-32 Absolute Maximum Ratings

Item	Symbol	Value	Unit
Power supply voltage	V _{cc}	-0.3 to +7.0	V
Input voltage (FWE)*1	V _{in}	-0.3 to V _{cc} +0.3	V
Input voltage (except port 4)*1	V_{in}	-0.3 to V _{cc} +0.3	V
Input voltage (port 4)*1	V_{in}	-0.3 to AV _{CC} +0.3	V
Reference voltage	V_{ref}	-0.3 to AV _{CC} +0.3	V
Analog power supply voltage	AV _{cc}	-0.3 to +7.0	V
Analog input voltage	V_{AN}	-0.3 to AV _{cc} +0.3	V
Operating temperature	T_{opr}	Regular specifications: –20 to +75*2	°C
		Wide-range specifications: -40 to +85*2	°C
Storage temperature	T _{stg}	-55 to +125	°C

Caution: Permanent damage to the chip may result if absolute maximum rating are exceeded.

Notes: 1. 12 V must not be applied to any pin, as this will cause permanent damage to the chip.

2. The operating temperature ranges for flash memory programming/erasing are as follows: $T_a = 0$ to +75°C (regular specifications), $T_a = 0$ to +85°C (wide-range specifications).

22.7.2 DC Characteristics

Table 22-33 lists the DC characteristics. Table 22-34 lists the permissible output currents.

Table 22-33 DC Characteristics (1)

Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}^{*1}$, $T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications), $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V_{T}^{-}	1.0	_	_	V	
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	$V_{T}^{}^{+}}$	_	_	$\rm V_{\rm CC} \times 0.7$	V	
Tonago	1 714 10 1 717	$\overline{V_T^+ - V_T^-}$	0.4	_	_	V	
Input high voltage	$\overline{\rm RES}, \overline{\rm STBY}, \\ {\rm NMI, MD}_2 \\ {\rm to MD}_0, {\rm FWE}$	V_{IH}	V _{cc} – 0.7	_	V _{cc} + 0.3	V	_
	EXTAL	_	$V_{\text{CC}} \times 0.7$	_	$V_{cc} + 0.3$	V	_
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃		2.0	_	V _{cc} + 0.3	V	
	Port4		2.0	_	$AV_{CC} + 0.3$	3 V	
Input low voltage	$\overline{\text{RES}}$, $\overline{\text{STBY}}$, MD_2 to MD_0 , FWE	V_{IL}	-0.3	_	0.5	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃	-	-0.3	_	0.8	V	_
Output high	All output pins	V _{OH}	V _{cc} - 0.5	_	_	V	I _{OH} = -200 μA
voltage			3.5	_	_	V	$I_{OH} = -1 \text{ mA}$
Output low	All output pins	V_{OL}	_	_	0.4	V	$I_{OL} = 1.6 \text{ mA}$
voltage	Port 1, A to C		_	_	1.0	V	$I_{OL} = 10 \text{ mA}$
Input leakage	RES	_ _{in}		_	10.0	μΑ	V _{in} =
current	$\overline{\text{STBY}}$, NMI, MD ₂ to MD ₀ , FWE	_	_	_	1.0	μA	0.5 to V _{cc} – 0.5 V
	Port 4		_	_	1.0	μA	$V_{in} = 0.5 \text{ to } AV_{CC} - 0.5 \text{ V}$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } V_{CC} - 0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	50	_	300	μΑ	$V_{in} = 0 V$
Input	RES	C_{in}	_	_	80	pF	$V_{in} = 0 V$
capacitance	NMI		_	_	50	pF	f = 1 MHz T a = 25°C
	All input pins except RES and NMI	_	_	_	15	pF	_
Current dissipation*2	Normal operation	I cc*4	_	78 (5.0 V)	122	mA	f = 20 MHz
	Sleep mode		_	53 (5.0 V)	84	mA	f = 20 MHz
	Standby	-	_	0.01	5.0	μΑ	T _a 50°C
	mode*3	_	_	_	20.0		50°C < T _a
	Flash memory programming/ erasing		_	88 (5.0 V)	122	mA	0°C T _a 75°C f = 20 MHz
Analog power supply current	During A/D and D/A conversion	Al _{cc}	_	0.8 (5.0 V)	2.0	mA	_
	Idle		_	0.01	5.0	μΑ	
Reference current	During A/D and D/A conversion	Al _{cc}	_	2.3 (5.0 V)	3.0	mA	
	Idle	=	_	0.01	5.0	μΑ	_
RAM standby v	oltage	V_{RAM}	2.0			V	

Notes: 1. If the A/D and D/A converters are not used,do not leave the AV_{CC}, AV_{ss}, and V_{ref} pins open.

Connect AV_{cc} and V_{ref} to V_{cc} , and connect AV_{ss} to V_{ss} .

- 2. Current dissipation values are for $V_{\rm IH}$ min = $V_{\rm CC}$ –0.5 V and $V_{\rm IL}$ max = 0.5V with all output pins unloaded and the on-chip pull-up transistors in the off state.
- 3. The values are for V_{RAM} V_{CC} < 4.5V, V_{IH} min = V_{CC} × 0.9, and V_{IL} max = 0.3 V.
- 4. I_{cc} depends on V_{cc} and f as follows:

 I_{cc} max = 1.0 (mA) + 1.1 (mA/(MHz × V)) × V_{cc} × f [normal mode]

 I_{cc} max = 1.0 (mA) + 0.75 (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-33 DC Characteristics (2)

Conditions: $V_{CC} = 3.0$ to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V*1, $T_a = -20$ to +75°C (regular specifications), $T_a = -40$ to +85°C (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Schmitt	Port 2,	V _T	$V_{\text{CC}} \times 0.2$	_	_	V	_
trigger input voltage	$P6_4$ to $P6_7$, PA_4 to PA_7	V _T ⁺	_	_	$V_{\text{CC}} \times 0.7$	V	
voltago	. , , , , , , ,	$V_T^+ - V_T^-$	$V_{cc} \times 0.07$	_	_	V	
Input high voltage	$\overline{\text{RES}}, \overline{\text{STBY}},$ NMI, MD ₂ to MD ₀ , FWE	V _{IH}	V _{cc} × 0.9		V _{cc} +0.3	V	
	EXTAL		$V_{\text{CC}} \times 0.7$	_	V _{cc} +0.3	V	_
	Port 1, 3, 5, B to G, P6 ₀ to P6 ₃ , PA ₀ to PA ₃		$V_{cc} \times 0.7$	_	V _{cc} +0.3	V	_
	Port 4		$V_{\text{CC}}\times 0.7$	_	AV _{cc} +0.3	V	
Input low voltage	RES, STBY, MD ₂ to MD ₀ , FWE	V_{IL}	-0.3	_	$V_{cc} \times 0.1$	V	
	NMI, EXTAL, Port 1, 3 to 5, B to G, P6 ₀ to P6 ₃ ,		-0.3	_	$V_{cc} \times 0.2$	V	V _{cc} < 4.0 V
	PA ₀ to PA ₃				0.8	_	$V_{\rm CC} = 4.0 \text{ to } 5.5 \text{ V}$
Output high	All output pins	V _{OH}	V _{cc} – 0.5	_	_	V	$I_{OH} = -200 \mu A$
voltage			V _{cc} – 1.0	_	_	V	$I_{OH} = -1 \text{ mA}$
Output low	All output pins	V_{OL}		_	0.4	V	$I_{OL} = 1.6 \text{ mA}$
voltage	Port 1, A to C		_	_	1.0	V	V_{CC} 4 V $I_{OL} = 5 \text{ mA}$ 4.0 < V_{CC} 5.5 V $I_{OL} = 10 \text{ mA}$
Input leakage	RES	_{in}	_	_	10.0	μΑ	_ V _{in} =
current	STBY, NMI, MD ₂ to MD ₀ , FWE				1.0	μΑ	$^{-}$ 0.5 to V_{cc} $-$ 0.5V
	Port 4		_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } AV_{CC} - 0.5V$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Three-state leakage current (off state)	Port 1 to 3, 5, 6, A to G	I _{TSI}	_	_	1.0	μΑ	$V_{in} = 0.5 \text{ to } V_{CC} - 0.5 \text{ V}$
MOS input pull-up current	Port A to E	-I _P	10	_	300	μΑ	$V_{CC} = 3.0 \text{ V to}$ 5.5 V, $V_{in} = 0 \text{ V}$
Input	RES	C_{in}	_	_	80	pF	$V_{in} = 0 V$
capacitance	NMI	_	_	_	50	pF	f = 1 MHz Ta = 25°C
	All input pins except RES and NMI		_	_	15	pF	
Current dissipation*2	Normal operation	I _{CC} *4	_	32 (3.3 V)	80	mA	f = 13 MHz
	Sleep mode		_	22 (3.3 V)	55	mA	f = 13 MHz
	Standby	•	_	0.01	5.0	μΑ	T _a 50°C
	mode*3	_	_	_	20		50°C < T _a
	Flash memory programming/ erasing		_	42 (3.3 V)	80	mA	0°C T _a 75°C f = 13 MHz
Analog power supply current	During A/D and D/A conversion	Al _{cc}	_	0.3 (3.3 V)	2.0	mA	
	Idle		_	0.01	5.0	μΑ	
Reference current	During A/D and D/A conversion	Al _{cc}	_	1.6 (3.3 V)	3.0	mA	
	Idle	:	_	0.01	5.0	μΑ	_
RAM standby v	oltage	V_{RAM}	2.0	_	_	V	

Notes: 1. If the A/D and D/A converters are not used,do not leave the AV_{CC}, AV_{ss}, and V_{ref} pins open.

Connect AV_{cc} and V_{ref} to V_{cc} , and connect AV_{ss} to V_{ss} .

- 2. Current dissipation values are for $V_{\rm IH}$ min = $V_{\rm CC}$ –0.5 V and $V_{\rm IL}$ max = 0.5V with all output pins unloaded and the on-chip pull-up transistors in the off state.
- 3. The values are for V_{RAM} $V_{CC} < 3.0 \text{ V}$, V_{IH} min = $V_{CC} \times 0.9$, and V_{IL} max = 0.3V.
- 4. I_{cc} depends on V_{cc} and f as follows:

 I_{cc} max = 1.0 (mA) + 1.1 (mA/(MHz × V)) × V_{cc} × f [normal mode]

 I_{cc} max = 1.0 (mA) + 0.75 (mA/(MHz × V)) × V_{cc} × f [sleep mode]

Table 22-34 Permissible Output Currents

Conditions:
$$V_{CC} = 3.0$$
 to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $T_a = -20$ to $+75$ °C (regular specifications), $T_a = -40$ to $+85$ °C (wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit
Permissible output	Port 1, A to C	I _{OL}	_	_	10	mA
low current (per pin)	Other output pins	_	_	_	2.0	mA
Permissible output low current (total)	Total of 32 pins including port 1 and A to C	\sum I _{OL}	_	_	80	mA
	Total of all output pins, including the above	_	_	_	120	mA
Permissible output high current (per pin)	All output pins	-I _{OH}	_	_	2.0	mA
Permissible output high current (total)	Total of all output pins	$\sum -I_{OH}$	_	_	40	mA

Notes: 1. To protect chip reliability, do not exceed the output current values in table 22-34.

2. When driving a darlington pair or LED directly, always insert a current-limiting resistor in the output line, as show in figures 22-65 and 22-66.

22.7.3 AC Characteristics

(1) Clock Timing

Table 22-35 lists the clock timing

Table 22-35 Clock Timing

Condition B: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 2 \text{ to } 20 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C} \text{ (regular specifications)},$

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition C: $V_{CC} = 3.0$ to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 2 \text{ to } 13 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

		Con	dition B	Con	dition C		
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
Clock cycle time	t _{cyc}	50	500	76	500	ns	Figure 22-68
Clock high pulse width	t _{CH}	20	_	23	_	ns	
Clock low pulse width	t _{CL}	20	_	23	_	ns	_
Clock rise time	t _{Cr}	_	5	_	15	ns	
Clock fall time	t _{Cf}	_	5	_	15	ns	
Clock oscillator setting time at reset (crystal)	t osc1	10	_	20	_	ms	Figure 22-69
Clock oscillator setting time in software standby (crystal)	t osc2	10	_	20	_	ms	Figure 21-2
External clock output stabilization delay time	t DEXT	500	_	500	_	μs	Figure 22-69

(2) Control Signal Timing

Table 22-36 lists the control signal timing.

Table 22-36 Control Signal Timing

Condition B:
$$V_{CC} = 5.0 \text{ V} \pm 10\%$$
, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition C:
$$V_{CC} = 3.0$$
 to 5.5 V, $AV_{CC} = 3.0$ to 5.5 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V, $\emptyset = 2$ to 13 MHz, $T_a = -20$ to +75°C (regular specifications), $T_a = -40$ to +85°C (wide-range specifications)

		Cond	ition B	Condition C			
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
RES setup time	t _{RESS}	200	_	200	_	ns	Figure 22-70
RES pulse width	t _{RESW}	20	_	20		t _{cyc}	_
NMI setup time	t _{NMIS}	150	_	250	_	ns	Figure 22-71
NMI hold time	t _{NMIH}	10	_	10		_	
NMI pulse width (exiting software standby mode)	t _{NMIW}	200	_	200	_	ns	_
IRQ setup time	t IRQS	150	_	250	_	ns	
IRQ hold time	t _{IRQH}	10	_	10	_	ns	_
IRQ pulse width (exiting software standby mode)	t _{IRQW}	200	_	200	_	ns	_

(3) Bus Timing

Table 22-37 lists the bus timing.

Table 22-37 Bus Timing

Condition B: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 2 \text{ to } 20 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition C: $V_{CC} = 3.0 \text{ to } 5.5 \text{ V}, AV_{CC} = 3.0 \text{ to } 5.5 \text{ V}, V_{ref} = 3.0 \text{ V to } AV_{CC},$

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \phi = 2 \text{ to } 13 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C} \text{ (regular specifications)},$

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

		Cond	ition B	Condition C			
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
Address delay time	t _{AD}	_	20	_	40	ns	Figure 22-72 to
Address setup time	t _{AS}	0.5 × t _{cyc} – 15	_	0.5 × t _{cyc} - 30	_	ns	Figure 22-79
Address hold time	t _{AH}	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} – 20	_	ns	-
Precharge time	t _{PCH}	1.5 × t _{cyc} – 20	_	1.5 × t _{cyc} – 40	_	ns	-
CS delay time 1	t _{CSD1}	_	20	_	40	ns	
CS delay time 2	t _{CSD2}	_	20	_	40	ns	-
CS delay time 3	t _{CSD3}	_	25	_	40	ns	-
AS delay time	t ASD	_	20	_	40	ns	-
RD delay time 1	t _{RSD1}	_	20	_	40	ns	-
RD delay time 2	t _{RSD2}	_	20	_	40	ns	-
CAS delay time	t CASD	_	20	_	40	ns	-
Read data setup time	t _{RDS}	15	_	30	_	ns	-
Read data hold time	t _{RDH}	0	_	0	_	ns	-
Read data access time1	t ACC1	_	1.0 × t _{cyc} – 25	_	$1.0 \times t_{cyc} - 50$	ns	-
Read data access time2	t _{ACC2}	_	1.5 × t _{cyc} – 25	_	1.5 × t _{cyc} – 50	ns	-
Read data access time3	t ACC3	_	$2.0 \times t_{cyc} - 25$	_	$2.0 \times t_{cyc} - 50$	ns	

		Condi	ition B	Condition C			
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
Read data access time 4	t _{ACC4}	_	2.5 × t _{cyc} – 25	_	$2.5 \times t_{cyc} - 50$	ns	Figure 22-72 to Figure 22-79
Read data access time 5	t _{ACC5}	_	$3.0 \times \atop t_{\text{cyc}} - 25$	_	$3.0 \times t_{\rm cyc} - 50$	ns	_
WR delay time 1	t _{WRD1}	_	20	_	40	ns	
WR delay time 2	t _{WRD2}	_	20	_	40	ns	_
WR pulse width 1	t _{wsw1}	1.0 × t _{cyc} – 20	_	1.0 × t _{cyc} – 40	_	ns	_
WR pulse width 2	t _{wsw2}	1.5 × t _{cyc} – 20	_	1.5 × t _{cyc} – 40	_	ns	_
Write data delay time	t _{wdd}	_	30	_	60	ns	_
Write data setup time	t _{WDS}	0.5 × t _{cyc} – 20	_	0.5 × t _{cyc} - 36	_	ns	_
Write data hold time	t _{wdh}	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} – 20		ns	_
WR setup time	t _{wcs}	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} – 20	_	ns	_
WR hold time	t _{wch}	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} – 20	_	ns	_
CAS setup time	t _{CSR}	0.5 × t _{cyc} – 10	_	0.5 × t _{cyc} – 20	_	ns	Figure 22-76
WAIT setup time	t _{wts}	30	_	60	_	ns	Figure 22-74
WAIT hold time	t _{wth}	5	_	10	_	ns	_
BREQ setup time	t BRQS	30	_	60	_	ns	Figure 22-80
BACK delay time	t BACD	_	15	_	30	ns	_
Bus-floating time	t _{BZD}	_	50	_	100	ns	_
BREQO delay time	t BRQOD	_	30	_	60	ns	Figure 22-81

(4) DMAC Timing

Table 22-38 lists the DMAC timing.

Table 22-38 DMAC Timing

Condition B: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \phi = 2 \text{ to } 20 \text{ MHz}, T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition C: $V_{CC} = 3.0 \text{ V}$ to 5.5 V, $AV_{CC} = 3.0 \text{ V}$ to 5.5 V, $V_{ref} = 3.0 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 4.0 \text{ V}$

0V, \emptyset = 2 to 13 MHz, T_a = -20 to +75°C (regular specifications), T_a = -40 to +85°C

(wide-range specifications)

		Cond	ndition B Condition C				
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
DREQ setup time	t DRQS	30	_	40	_	ns	Figure 22-85
DREQ hold time	t DRQH	10	_	10	_	_	
TEND delay time	t _{TED}	_	20	_	40	_	Figure 22-84
DACK delay time 1	t DACD1	_	20	_	40	ns	Figure 22-82
DACK delay time 2	t DACD2	_	20	_	40	_	Figure 22-83

(5) Timing of On-Chip Supporting Modules

Table 22-39 lists the timing of on-chip supporting modules.

Table 22-39 Timing of On-Chip Supporting Modules

Condition B:
$$V_{CC} = 5.0 \text{ V} \pm 10\%$$
, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition C:
$$V_{CC} = 3.0 \text{ V}$$
 to 5.5 V, $AV_{CC} = 3.0 \text{ V}$ to 5.5 V, $V_{ref} = 3.0 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 13 MHz, $T_a = -20$ to $+75^{\circ}\text{C}$ (regular specifications), $T_a = -40$ to $+85^{\circ}\text{C}$ (wide-range specifications)

				Con	dition B	Con	dition C		Test
Item			Symbol	Min	Max	Min	Max	Unit	Conditions
PORT	Output data c	lelay time	t _{PWD}	_	50	_	75	ns	Figure 22-86
	Input data se	tup time	t _{PRS}	30	_	50	_	-	
	Input data ho	ld time	t _{PRH}	30	_	50	_	=	
PPG	Pulse output	delay time	t _{POD}	_	50	_	75	ns	Figure 22-87
TPU	Timer output	delay time	t TOCD	_	50	_	75	ns	Figure 22-88
	Timer input s	etup time	t TICS	30	_	50	_	=	
	Timer clock in time	nput setup	t _{TCKS}	30	_	50	_	ns	Figure 22-89
	Timer clock pulse width	Single edge	t _{TCKWH}	1.5	_	1.5	_	t _{cyc}	_
		Both edges	t _{TCKWL}	2.5	_	2.5	_	-	
TMR	Timer output	delay time	t _{TMOD}	_	50	_	75	ns	Figure 22-90
	Timer reset in time	put setup	t _{TMRS}	30	_	50	_	ns	Figure 22-92
	Timer clock in time	nput setup	t _{TMCS}	30	_	50	_	ns	Figure 22-91
	Timer clock pulse width	Single edge	t _{TMCWH}	1.5	_	1.5	_	t _{cyc}	
		Both edges	t _{TMCWL}	2.5		2.5			

				Con	dition B	Con	dition C		Test
Item			Symbol	Min	Max	Min	Max	Unit	Conditions
SCI	Input clock cycle	Asynchro- nous	t _{Scyc}	4	_	4	_	t _{cyc}	Figure 22-94
		Synchro- nous	_	6	_	6	_	-	
	Input clock p	ulse width	t _{SCKW}	0.4	0.6	0.4	0.6	t scyc	_
	Input clock ri	ise time	t _{SCKr}	_	1.5	_	1.5	t _{cyc}	
	Input clock fa	all time	t _{SCKf}	_	1.5	_	1.5	-	
	Transmit dat time	a delay	t _{TXD}	_	50	_	75	ns	Figure 22-95
	Receive data time (synchr	•	t _{RXS}	50	_	75	_	ns	_
	Receive data time (synchr		t _{RXH}	50	_	75	_	ns	_
A/D converter	Trigger input	t setup	t _{TRGS}	30	_	50	_	ns	Figure 22-96

22.7.4 A/D Conversion Characteristics

Table 22-40 lists the A/D conversion characteristics.

Table 22-40 A/D Conversion Characteristics

Condition B:
$$V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$$
, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications), $T_a = -40$ to $+85^{\circ}C$ (wide-range specifications)

Condition C:
$$V_{CC} = AV_{CC} = 3.0 \text{ V}$$
 to 5.5 V, $V_{ref} = 3.0 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 13 MHz, $T_a = -20$ to $+75^{\circ}$ C (regular specifications), $T_a = -40$ to $+85^{\circ}$ C (wide-range specifications)

		Condition	on B		Condition	on C	
Item	Min	Тур	Max	Min	Тур	Max	Unit
Resolution	10	10	10	10	10	10	bits
Conversion time	6.7	_	_	10.4	_	_	μs
Analog input capacitance	_	_	20	_	_	20	pF
Permissible signal-source	_	_	10*3	_	_	10* ¹	k
impedance	_	_	5*4	_	_	5* ²	
Nonlinearity error	_	_	±3.5	_	_	±7.5	LSB
Offset error	_	_	±3.5	_	_	±7.5	LSB
Full-scale error	_	_	±3.5	_	_	±7.5	LSB
Quantization	_	_	±0.5	_	_	±0.5	LSB
Absolute accuracy	_	_	±4.0	_	_	±8.0	LSB

Notes: 1. 4.0 V AV cc 5.5 V

2. 3.0 V AV $_{\text{CC}} < 4.0 \text{ V}$

3. ø 12 MHz

4. ø > 12 MHz

22.7.5 D/A Conversion Characteristics

Table 22-41 lists the D/A conversion characteristics

Table 22-41 D/A Conversion Characteristics

Condition B: $V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0 \text{ V}$, $\emptyset = 2$ to 20 MHz, $T_a = -20$ to $+75^{\circ}C$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

Condition C: $V_{CC} = AV_{CC} = 3.0 \text{ V}$ to 5.5 V, $V_{ref} = 3.0 \text{ V}$ to AV_{CC} ,

 $V_{SS} = AV_{SS} = 0 \text{ V}, \ \emptyset = 2 \text{ to } 13 \text{ MHz}, \ T_a = -20 \text{ to } +75^{\circ}\text{C}$ (regular specifications),

 $T_a = -40 \text{ to } +85^{\circ}\text{C}$ (wide-range specifications)

	C	Conditio	n B	(Condition	on C		
Item	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Resolution	8	8	8	8	8	8	bit	
Conversion time	_	_	10	_	_	10	μs	20-pF capacitive load
Absolute accuracy	_	±1.0	±1.5	_	±2.0	±3.0	LSB	2-M resistive load
	_	_	±1.0	_	_	±2.0	LSB	4-M resistive load

22.7.6 Flash Memory Characteristics

Table 22-42 shows the flash memory characteristics.

Table 22-42 Flash Memory Characteristics (1)

Conditions: $V_{CC} = 5.0 \text{ V} \pm 10\%$, $AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{ref} = 4.5 \text{ V}$ to AV_{CC} , $V_{SS} = AV_{SS} = 0V$

 $T_a = 0$ to +75°C (Programming/erasing operating temperature, regular

specifications), T_a = 0 to + 85°C (Programming/erasing operating temperature,

wide-range specifications)

Item		Symbol	Min	Тур	Max	Unit	Test Condition
Programming	time* ^{1,} * ^{2,} * ⁴	t _P	_	10	200	ms/32 bytes	3
Erase time*1,*	3,*5	t _E	_	100	1200	ms/block	
Reprogrammi	ng count	N _{WEC}	_	_	100	Times	
Programming	Wait time after SWE bit setting*1	Х	10	_	_	μs	
	Wait time after PSU bit setting*1	У	50	_	_	μs	
	Wait time after P bit setting*1, *4	Z	150	_	200	μs	
	Wait time after P bit clear*1	α	10	_	_	μs	
	Wait time after PSU bit clear*1	β	10	_	_	μs	
	Wait time after PV bit setting*1	γ	4	_	_	μs	
	Wait time after H'FF dummy write*1	ε	2	_	_	μs	
	Wait time after PV bit clear*	¹η	4	_	_	μs	
	Maximum programming count*1,*4	N	_	_	1000*5	Times	z = 200 µs

Item		Symbol	Min	Тур	Max	Unit	Test Condition
Erase	Wait time after SWE bit setting*1	Х	10	_	_	μs	
	Wait time after ESU bit setting*1	у	200	_	_	μs	
	Wait time after E bit setting* ^{1,} * ⁶	Z	5	_	10	ms	
	Wait time after E bit clear*1	α	10	_	_	μs	
	Wait time after ESU bit clear*1	β	10	_	_	μs	
	Wait time after EV bit setting*1	γ	20	_	_	μs	
	Wait time after H'FF dummy write*1	<i>ι</i> ε	2	_	_	μs	
	Wait time after EV bit clear*	^{:1} η	5	_	_	μs	
	Maximum erase count*1,*6	N	120	_	240	Times	

Notes: 1. Set the times according to the program/erase algorithms.

- 2. Programming time per 32 bytes (Shows the total time the flash memory control register 1 (FLMCR1) is set. It does not include the programming verification time.)
- 3. Block erase time (Shows the period the E bit in FLMCR1 is set. It does not include the erase verification time.)
- 4. Maximum programming time (t_n (max)=wait time after P-bit setting (z) × maximum programming count (N))
- Number of times when the wait time after P bit setting (z) = 200 μs.
 The maximum number of writes (N) should be set according to the actual set value of z so as not to exceed the maximum programming time (t_P(max)).
- 6. For the maximum erase time ($t_E(max)$), the following relationship applies between the wait time after E bit setting (z) and the maximum number of erases (N):

 $t_E(max)$ = Wait time after E bit setting (z) x maximum number of erases (N)

The values of z and N should be set so as to satisfy the above formula.

Examples: When
$$z = 5$$
 [ms], $N = 240$ times
When $z = 10$ [ms], $N = 120$ times

Table 22-42 shows the flash memory characteristics.

Table 22-42 Flash Memory Characteristics (2)

Conditions: $V_{CC} = 3.0$ to 3.6 V, $AV_{CC} = 3.0$ to 3.6 V, $V_{ref} = 3.0$ V to AV_{CC} , $V_{SS} = AV_{SS} = 0$ V

T_a=0 to +75°C (Programming/erasing operating temperature, regular

specifications), T_a=0 to +85°C (Programming/erasing operating temperature,

wide-range specifications)

Item		Symbo	l Min	Тур	Max	Unit	Test Condition
Programming	time*1,*2,*4	t _P	_	10	200	ms/32 bytes	
Erase time*1,*	;3, _* 5	t _E	_	100	1200	ms/block	
Reprogrammi	ng count	N_{WEC}	_	_	100	Times	
	Wait time after SWE bit setting*1	х	10	_	_	μs	
	Wait time after PSU bit setting*1	у	50	_	_	μs	
	Wait time after P bit setting*1, *4	Z	150	_	200	μs	
	Wait time after P bit clear*1	α	10	_		μs	
Programming	Wait time after PSU bit clear*1	β	10	_	_	μs	
	Wait time after PV bit setting*1	γ	4	_	_	μs	
	Wait time after H'FF dummy write*1	ε	2	_	_	μs	
	Wait time after PV bit clear*1	' η	4	_	_	μs	
	Maximum programming count*1,*4	N	_	_	1000*	⁵ Times	Z = 200μs

Item		Symbol	Min	Тур	Max	Unit	Test Condition
	Wait time after SWE bit setting*1	х	10	_	_	μs	
	Wait time after ESU bit setting*1	у	200	_	_	μs	
	Wait time after E bit setting* ^{1,*6}	Z	5	_	10	ms	
Erase	Wait time after E bit clear*1	α	10	_	_	μs	
	Wait time after ESU bit clear*1	β	10	_	_	μs	
	Wait time after EV bit setting*1	γ	20	_	_	μs	
	Wait time after H'FF dummy write*1	/ ε	2	_	_	μs	
	Wait time after EV bit clear*	¹ η	5	_	_	μs	
	Maximum erase count*1,*6	N	120	_	240	Times	

Notes: 1. Set the times according to the program/erase algorithms.

- 2. Programming time per 32 bytes (Shows the total time the flash memory control register (FLMCR) is set. It does not include the programming verification time.)
- 3. Block erase time (Shows the period the E bit in FLMCR is set. It does not include the erase verification time.)
- 4. Maximum programming time (t₀ (max)=wait time after P-bit setting (Z) × maximum programming count (N))
- Number of times when the wait time after P bit setting (z) = 200 μs.
 The maximum number of writes (N) should be set according to the actual set value of z so as not to exceed the maximum programming time (t_P(max)).
- 6. For the maximum erase time (t_E(max)), the following relationship applies between the wait time after E bit setting (z) and the maximum number of erases (N):

 $t_E(max)$ = Wait time after E bit setting (z) x maximum number of erases (N)

The values of \boldsymbol{z} and \boldsymbol{N} should be set so as to satisfy the above formula.

Examples: When z = 5 [ms], N = 240 times When z = 10 [ms], N = 120 times

22.8 Usage Note

Although the ZTAT, F-ZTAT, and mask ROM versions fully meet the electrical specifications listed in this manual, due to differences in the fabrication process, the on-chip ROM, and the layout patterns, there will be differences in the actual values of the electrical characteristics, the operating margins, the noise margins, and other aspects.

Therefore, if a system is evaluated using the ZTAT and F-ZTAT versions, a similar evaluation should also be performed using the mask ROM version.

Appendix A Instruction Set

A.1 Instruction List

Operand Notation

Rd	General register (destination)*1
Rs	General register (source)*1
Rn	General register*1
ERn	General register (32-bit register)
MAC	Multiply-and-accumulate register (32-bit register)*2
(EAd)	Destination operand
(EAs)	Source operand
EXR	Extended control register
CCR	Condition-code register
N	N (negative) flag in CCR
Z	Z (zero) flag in CCR
V	V (overflow) flag in CCR
С	C (carry) flag in CCR
PC	Program counter
SP	Stack pointer
#IMM	Immediate data
disp	Displacement
+	Add
_	Subtract
×	Multiply
÷	Divide
٨	Logical AND
V	Logical OR
\oplus	Logical exclusive OR
\rightarrow	Transfer from the operand on the left to the operand on the right, or transition from the state on the left to the state on the right
7	Logical NOT (logical complement)
() < >	Contents of operand
:8/:16/:24/:32	8-, 16-, 24-, or 32-bit length

Notes: 1. General registers include 8-bit registers (R0H to R7H, R0L to R7L), 16-bit registers (R0 to R7, E0 to E7), and 32-bit registers (ER0 to ER7).

2. The MAC register cannot be used in the H8S/2357 Series.

Condition Code Notation

Symbol

\(\)	Changes according to the result of instruction
*	Undetermined (no guaranteed value)
0	Always cleared to 0
1	Always set to 1
_	Not affected by execution of the instruction

Table A-1 Instruction Set

(1) Data Transfer Instructions

			nst	Addressing Mode/ Instruction Length (Bytes)	Addressing Mode/ ruction Length (By	sin(Len	J Mc	de/ (By	tes)								
		ezi2 bns1		L L L	hERn)	+uA∃@\nA∃		()d'r	999			ទី	Condition Code	ion	Š	ā	No. of States*1
	Mnemonic		XX#	шЯ @Е			@ 9		 (0) (0)	Operation		_	z	Z	>	ပ	Advanced
MOV	MOV.B #xx:8,Rd	В	2							#xx:8→Rd8			\leftrightarrow	\leftrightarrow	0	I	7
	MOV.B Rs,Rd	В	. 4	2						Rs8→Rd8			$\stackrel{\longleftrightarrow}{}$	\leftrightarrow	0	Ι	1
	MOV.B @ERs,Rd	В		2						@ERs→Rd8			\leftrightarrow	\leftrightarrow	0	Ι	2
	MOV.B @(d:16,ERs),Rd	В			4					@(d:16,ERs)→Rd8			\leftrightarrow	\leftrightarrow	0	I	3
	MOV.B @(d:32,ERs),Rd	В			8					@(d:32,ERs)→Rd8			\leftrightarrow	\leftrightarrow	0	Ι	5
	MOV.B @ERs+,Rd	В				2				@ERs→Rd8,ERs32+1→ERs32	332	<u> </u>	\leftrightarrow	\leftrightarrow	0	Ι	3
	MOV.B @aa:8,Rd	В					7			@aa:8→Rd8			\leftrightarrow	\leftrightarrow	0	Ι	2
	MOV.B @aa:16,Rd	В					4			@aa:16→Rd8		<u> </u>	\leftrightarrow	\leftrightarrow	0	Ι	3
	MOV.B @aa:32,Rd	В					9			@aa:32→Rd8			\leftrightarrow	\leftrightarrow	0	Ι	4
	MOV.B Rs,@ERd	В		2						Rs8→@ERd			\leftrightarrow	\leftrightarrow	0	I	2
	MOV.B Rs, @ (d:16,ERd)	В			4					Rs8→@(d:16,ERd)		+	\leftrightarrow	\leftrightarrow	0	Ι	3
	MOV.B Rs, @ (d:32, ERd)	В			8					Rs8→@(d:32,ERd)		<u> </u>	\leftrightarrow	\leftrightarrow	0	Ι	5
	MOV.B Rs,@-ERd	В				2				ERd32-1→ERd32,Rs8→@ERd	Rd		\leftrightarrow	\leftrightarrow	0	Ι	3
	MOV.B Rs,@aa:8	В					2			Rs8→@aa:8			$\stackrel{\longleftrightarrow}{}$	\leftrightarrow	0	Ι	2
	MOV.B Rs,@aa:16	В					4			Rs8→@aa:16		$^{+}$	\leftrightarrow	\leftrightarrow	0	Τ	3
	MOV.B Rs,@aa:32	В					9			Rs8→@aa:32		\dagger	\leftrightarrow	\leftrightarrow	0	Ι	4
	MOV.W #xx:16,Rd	W	4							#xx:16→Rd16			$\stackrel{\longleftrightarrow}{\overline{\Box}}$	\leftrightarrow	0	Ι	2
	MOV.W Rs,Rd	8	• •	2						Rs16→Rd16			$\stackrel{\longleftrightarrow}{\overline{\hspace{1em}}}$	\leftrightarrow	0	Ι	1
	MOV.W @ERs,Rd	>		7						@ERs→Rd16		1	\leftrightarrow	\leftrightarrow	0	Ι	2

			Inst	Ad	dres	ssin Lei	Addressing Mode/ ruction Length (By	ode (B)	Addressing Mode/ Instruction Length (Bytes)								
		erand Size		uы	(nA∃,t	ERn/@ERn+		(Ja,	999			S	Condition Code	on (000	Φ	No. of States*¹
	Mnemonic		XX#	wE Bu			œ9) (D)	Operation	•	_	z	7	>	ပ	Advanced
NOM	MOV.W @(d:16,ERs),Rd	>			4					@(d:16,ERs)→Rd16			\leftrightarrow	\leftrightarrow	0		3
	MOV.W @(d:32,ERs),Rd	8			8					@(d:32,ERs)→Rd16			\leftrightarrow	\leftrightarrow	0	1	5
	MOV.W @ERs+,Rd	>				2				@ERs→Rd16,ERs32+2→ERs32	Rs32		\leftrightarrow	\leftrightarrow	0	I	3
	MOV.W @aa:16,Rd	≥					4			@aa:16→Rd16			\leftrightarrow	\leftrightarrow	0		က
	MOV.W @aa:32,Rd	≥					9			@aa:32→Rd16			\leftrightarrow	\leftrightarrow	0		4
	MOV.W Rs,@ERd	≥		.,	7					Rs16→@ERd			\leftrightarrow	\leftrightarrow	0		2
	MOV.W Rs, @ (d:16,ERd)	>			4					Rs16→@(d:16,ERd)			\leftrightarrow	\leftrightarrow	0		3
	MOV.W Rs, @ (d:32, ERd)	8			8					Rs16→@(d:32,ERd)			\leftrightarrow	\leftrightarrow	0	Ι	5
	MOV.W Rs,@-ERd	8				2				ERd32-2→ERd32,Rs16→@ERd	ERd		\leftrightarrow	\leftrightarrow	0	1	3
	MOV.W Rs,@aa:16	8					4			Rs16→@aa:16			\leftrightarrow	\leftrightarrow	0		3
	MOV.W Rs,@aa:32	>					9			Rs16→@aa:32			\leftrightarrow	\leftrightarrow	0		4
	MOV.L #xx:32,ERd	_	9							#xx:32→ERd32			\leftrightarrow	\leftrightarrow	0		ဇ
	MOV.L ERS,ERd	_		2						ERs32→ERd32			\leftrightarrow	\leftrightarrow	0		1
	MOV.L @ERs,ERd	Г		7	4					@ERs→ERd32			\leftrightarrow	\leftrightarrow	0		4
	MOV.L @(d:16,ERs),ERd	_			9					@(d:16,ERs)→ERd32		<u> </u>	\leftrightarrow	\leftrightarrow	0		5
	MOV.L @(d:32,ERs),ERd	_			10					@(d:32,ERs)→ERd32			\leftrightarrow	\leftrightarrow	0		7
	MOV.L @ERs+,ERd	_				4				@ERs→ERd32,ERs32+4→@ERs32	332		\leftrightarrow	\leftrightarrow	0		5
	MOV.L @aa:16,ERd	_					9			@aa:16→ERd32		1	\leftrightarrow	\leftrightarrow	0		5
	MOV.L @aa:32,ERd		-				∞	-		@aa:32→ERd32			\leftrightarrow	\leftrightarrow	0		9

			lus	Ad	dre	Addressing Mode/ Instruction Length (Bytes)	g M	ode (B)	/ /tes							
		erand Size			др. д,ЕRn)	-ERn/@ERn+		(J 9,	@ 99			Condition Code	ion	Š	e O	No. of States*1
	Mnemonic		XX#	иЯ			@		0 0	Operation	ion	I I	Z	>	ပ	Advanced
MOV	MOV.L ERs, @ERd	٦			4					ERs32→@ERd		↔ 	\leftrightarrow	0	I	4
	MOV.L ERs, @(d:16,ERd)	7			9					ERs32→@(d:16,ERd)	Rd)		\leftrightarrow	0	I	2
	MOV.L ERs, @(d:32,ERd)	٦			10					ERs32→@(d:32,ERd)	Rd)	<u></u>	\leftrightarrow	0	1	2
	MOV.L ERs, @-ERd	٦				4				ERd32-4→ERd32,ERs32→@ERd	:Rs32→@ERd	→	\leftrightarrow	0	-	2
	MOV.L ERs,@aa:16	_					9			ERs32→@aa:16		 	\leftrightarrow	0	-	2
	MOV.L ERs, @aa:32	_					8			ERs32→@aa:32		<> 	\leftrightarrow	0	I	9
POP	POP.W Rn	≥							2	@SP→Rn16,SP+2→SP	S→SP		\leftrightarrow	0	1	ဇ
	POP.L ERn	٦							4	@SP→ERn32,SP+4→SP	-4→SP		\leftrightarrow	0	1	2
PUSH	PUSH.W Rn	8							2	SP-2→SP,Rn16→@SP	@SP	<u></u>	\leftrightarrow	0	1	3
	PUSH.L ERn	٦							4	SP-4→SP,ERn32→@SP	→@SP	→	\leftrightarrow	0	-	2
ГРМ	LDM @SP+,(ERm-ERn)	٦							4	(@SP→ERn32,SP+4→SP)	'+4→SP)		1			7/9/11 [1]
										Repeated for each register restored	gister restored					
STM	STM (ERm-ERn), @-SP	_							4	(SP-4→SP,ERn32→@SP)	→@SP)		1			7/9/11 [1]
										Repeated for each register saved	register saved					
MOVFPE	MOVFPE @aa:16,Rd	Car	not	t be	nse	d in	the	_48S	/23	Cannot be used in the H8S/2357 Series						[2]
MOVTPE	MOVTPE Rs,@aa:16	Car	Jour	t be	nse	Ę.	the	월 	/23	Cannot be used in the H8S/2357 Series						[2]

(2) Arithmetic Instructions

			lnst	Adj	Addressing Mode/ Instruction Length (Bytes)	sing Len	Mo gth (de/ Byt	(se							
		erand Size	;	นษา	(nA∃,b	+u为3@/u为3		ges ()	n= C		Co	Condition Code	on	Çoq	<u>•</u>	No. of States* ¹
	Mnemonic		XX#	шЯ @Е		-@	60a		_	Operation	-	z	7	>	ပ	Advanced
ADD	ADD.B #xx:8,Rd	В	2							Rd8+#xx:8→Rd8	< <u></u>	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	ADD.B Rs,Rd	В	- 1	2						Rd8+Rs8→Rd8	< <u></u>	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	ADD.W #xx:16,Rd	>	4							Rd16+#xx:16→Rd16	<u> </u>	\$ [2]	\leftrightarrow	\leftrightarrow	\leftrightarrow	2
	ADD.W Rs,Rd	>	- •	2						Rd16+Rs16→Rd16	<u>=</u>	(3]	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	ADD.L #xx:32,ERd	٦	9							ERd32+#xx:32→ERd32	- [4	[4]	\leftrightarrow	\leftrightarrow	\leftrightarrow	3
	ADD.L ERS,ERd	_	- 1	2						ERd32+ERs32→ERd32	<u>-</u>	[4]	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
ADDX	ADDX #xx:8,Rd	В	2							Rd8+#xx:8+C→Rd8	<u>↔</u> 	\leftrightarrow	[2]	\leftrightarrow	\leftrightarrow	1
	ADDX Rs,Rd	В		2						Rd8+Rs8+C→Rd8	↔ 	\leftrightarrow	[2]	\leftrightarrow	\leftrightarrow	1
ADDS	ADDS #1,ERd	_	- 1	2						ERd32+1→ERd32	1				Ι	1
	ADDS #2,ERd	_	-	2						ERd32+2→ERd32					I	1
	ADDS #4,ERd	_	- •	7						ERd32+4→ERd32	1			1	I	_
INC	INC.B Rd	В	- 1	2						Rd8+1→Rd8		\leftrightarrow	\leftrightarrow	\leftrightarrow	Ι	1
	INC.W #1,Rd	8	- 1	2						Rd16+1→Rd16		\leftrightarrow	\leftrightarrow	\leftrightarrow	Ι	1
	INC.W #2,Rd	>	• •	2						Rd16+2→Rd16	1	\leftrightarrow	\leftrightarrow	\leftrightarrow	Ι	1
	INC.L #1,ERd	_	- 1	2						ERd32+1→ERd32		\leftrightarrow	\leftrightarrow	\leftrightarrow	Ι	1
	INC.L #2,ERd	_	- 1	2						ERd32+2→ERd32	1	\leftrightarrow	\leftrightarrow	\leftrightarrow	Τ	1
DAA	DAA Rd	В	- 1	2						Rd8 decimal adjust→Rd8	*	\leftrightarrow	\leftrightarrow	*	\leftrightarrow	1
SUB	SUB.B Rs,Rd	В	- 1	2						Rd8-Rs8→Rd8	< <u></u>	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	SUB.W #xx:16,Rd	>	4					\dashv		Rd16-#xx:16→Rd16	<u> </u>	⇒ [3]	\leftrightarrow	\leftrightarrow	\leftrightarrow	2

			lns	Ad	dres	sing Len	Addressing Mode/ Instruction Length (Bytes)	de/ (Byt	(sa							
		eziS bnare		Вп	(nA3-t	+uA∃@/uA∃) aa				ā	Condition Code	Š	e e	No. of States*¹
	Mnemonic		XX#	©E Bu		-@	60a		_	Operation		I	N	>	ပ	Advanced
SUB	SUB.W Rs,Rd	>		2						Rd16-Rs16→Rd16		[3]	\leftrightarrow	\leftrightarrow	\leftrightarrow	-
	SUB.L #xx:32,ERd	٦	9							ERd32-#xx:32→ERd32	Ī	[4]	\leftrightarrow	\leftrightarrow	\leftrightarrow	8
	SUB.L ERs,ERd	٦	• •	2						ERd32-ERs32→ERd32	1	[4]	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
SUBX	SUBX #xx:8,Rd	В	7							Rd8-#xx:8-C→Rd8		\leftrightarrow	‡ [5]	⇔ [5	\leftrightarrow	1
	SUBX Rs,Rd	В	• •	7						Rd8-Rs8-C→Rd8	Ī	\leftrightarrow	\$ 12	0 (2)	\leftrightarrow	1
SUBS	SUBS #1,ERd	_	. 1	2						ERd32-1→ERd32			<u> </u> -		1	1
	SUBS #2,ERd	_	• •	2						ERd32-2→ERd32	İ	<u> </u>	<u> </u> 	<u> </u>		1
	SUBS #4,ERd	L	• •	2						ERd32-4→ERd32			<u> </u>			1
DEC	DEC.B Rd	В	• •	2						Rd8-1→Rd8	1	$\frac{1}{1}$	\leftrightarrow	\leftrightarrow		1
	DEC.W #1,Rd	Μ	. 1	2						Rd16-1→Rd16	İ	1	\leftrightarrow	\leftrightarrow		1
	DEC.W #2,Rd	8	. 1	2						Rd16-2→Rd16			\leftrightarrow	\leftrightarrow		1
	DEC.L #1,ERd	_	. 1	2						ERd32-1→ERd32			\leftrightarrow	\leftrightarrow		1
	DEC.L #2,ERd	٦	. 1	2						ERd32-2→ERd32			\leftrightarrow	\leftrightarrow		1
DAS	DAS Rd	В	• •	2						Rd8 decimal adjust→Rd8		*	\leftrightarrow	*		1
MULXU	MULXU.B Rs,Rd	В	• •	2						Rd8×Rs8→Rd16 (unsigned multiplication)		+				12
	MULXU.W Rs,ERd	≷	••	7						Rd16×Rs16→ERd32	1	<u> </u>	1	1		20
										(unsigned multiplication)			_			
MULXS	MULXS.B Rs,Rd	В		4						Rd8×Rs8→Rd16 (signed multiplication)	1	\7	\leftrightarrow \leftrightarrow	1	_	13
	MULXS.W Rs,ERd	≥	•	4						Rd16×Rs16→ERd32	İ	1	$\leftrightarrow \longleftrightarrow$	1		21
										(signed multiplication)						
			l									l		l		

		_	nstr	Add	ressi on L	Addressing Mode/ Instruction Length (Bytes)	lode h (B	ytes					
		erand Size		นษา	d,ERn)	g EKn/@EKn+	(Ja'r	999	Condition Code	tion	S	<u>o</u>	No. of States* ¹
	Mnemonic		ww #xx			@9 @9		0 0	Operation I H N	N	>	ပ	Advanced
DIVXU	DIVXU.B Rs,Rd	В	2						Rd16÷Rs8→Rd16 (RdH: remainder, — — [6	[6]]	Ι	12
									RdL: quotient) (unsigned division)				
	DIVXU.W Rs,ERd	>	7						ERd32÷Rs16→ERd32 (Ed: remainder, —	[6]	_	I	20
									Rd: quotient) (unsigned division)				
DIVXS	divxs.B Rs,Rd	В	4						Rd16÷Rs8→Rd16 (RdH: remainder, — — [8	[8]]	I	13
									RdL: quotient) (signed division)				
	DIVXS.W Rs,ERd	>	4						ERd32÷Rs16→ERd32 (Ed: remainder, — — [8	[8]		1	21
									Rd: quotient) (signed division)				
CMP	CMP.B #xx:8,Rd	B 2							Rd8-#xx:8 $-$	\leftrightarrow	\leftrightarrow	\leftrightarrow	-
	CMP.B Rs,Rd	В	2						Rd8-Rs8 $-$	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	CMP.W #xx:16,Rd	W							Rd16-#xx:16 — [3] ↑	\leftrightarrow	\leftrightarrow	\leftrightarrow	2
	CMP.W Rs,Rd	>	7						Rd16-Rs16 — [3] ↑	\leftrightarrow	\leftrightarrow	\leftrightarrow	-
	CMP.L #xx:32,ERd	9 T							ERd32-#xx:32 $-$ [4] \updownarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	8
	CMP.L ERS,ERd	_	7						ERd32-ERs32 $-$ [4] \updownarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	-
NEG	NEG.B Rd	В	2						0-Rd8→Rd8 —	\leftrightarrow	\leftrightarrow	\leftrightarrow	-
	NEG.W Rd	>	2						0-Rd16→Rd16 — ↑ ↑	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	NEG.L ERd		2						0-ERd32 \rightarrow ERd32 $-$	\leftrightarrow	\Rightarrow	\leftrightarrow	1
EXTU	EXTU.W Rd	>	7						$0 \rightarrow (< bit 15 to 8> of Rd16)$ $ 0$	 	0	Τ	1
	EXTU.L ERd	_	7					\dashv	$0 \rightarrow (< bit 31 \text{ to } 16 > of ERd32)$ $ 0$	 	0		-

			Addressing Mode/ Instruction Length (Bytes)	ddr Jetic	essi n Le	Addressing Mode/ ruction Length (By	ode (B)	/ /tes)				
		erand Size		иŊ	EBN/@EBN+ q'EBN)		(Ja'r	999	Condition Code	ition (ode	No. of States*1
	Mnemonic		#XX	∃@	(c	@9 @	@ (0	00	Operation I H N	N	C	Advanced
EXTS	EXTS.W Rd	8	2						(bit 7> of Rd16)→	\leftrightarrow	0	L
									(bit 15 to 8> of Rd16)			
	EXTS.L ERd	٦	2						(bit 15> of ERd32) \rightarrow — — (+	0	-
									(bit 31 to 16> of ERd32)			
TAS	TAS @ERd*3	В		4					@ERd-0→CCR set, (1)→ — — (1)	\leftrightarrow	0	4
									(<bit 7=""> of @ERd)</bit>			
MAC	MAC @ERn+, @ERm+	Can	ot b	e us	ed ir	the	H8S	/235	Cannot be used in the H8S/2357 Series			[2]
CLRMAC	CLRMAC											
LDMAC	LDMAC ERS,MACH	1										
	LDMAC ERS, MACL	П										
STMAC	STMAC MACH, ERd	ı										
	STMAC MACL,ERd											

(3) Logical Instructions

Sara Rad B Sara Rad			L] .	'	ľ		١.	F		L						
Mnemonic AND.B #xx:8,Rd AND.B #xx:8,Rd B 2 Rn AND.W Bxx:8,Rd AND.W Bxx:16,Rd W V 2 Rn @(d,PC) AND.W Bx,Rd W V Z Rn @(a,ERn) @(a,ERn) AND.L #xx:32,ERd L 6 Z Rn B Z Rn OR.W Bx,Rd W V A A A A A B </th <th></th> <th></th> <th></th> <th>lns</th> <th>it Ac</th> <th>i dre</th> <th>SSII n Le</th> <th>ıg r</th> <th>е Р В</th> <th>syte</th> <th>(S)</th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th>				lns	it Ac	i dre	SSII n Le	ıg r	е Р В	syte	(S)								
Mnemonic Op x E ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕ ⊕				,									ၓ	Şu Ç	iţi	ے	Condition Code		No. of States* ¹
AND.B #xx:8,Rd AND.B Rs,Rd AND.W Rs,Rd AND.W Rs,Rd AND.L #xx:32,ERd AND.L ERS,ERd OR.B Rx,Rd OR.W Rs,Rd OR.W Rs,Rd OR.U ERS,Rd OR.W Rs,Rd OR.U ERS,Rd OR.U ERS,Rd OR.W Rs,Rd OR.U ERS,Rd XOR.B Rx,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.U ERS,ERd C C C C C C C C C C C C C C C C C C C		Mnemonic			_						_	Operation	-	I	z	Z	ပ >		Advanced
AND.B.Rs,Rd AND.W.Rs,Rd AND.L.H.Xx:32,ERd OR.B.Rxx:8,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd OR.W.Rxx:16,Rd XOR.B.Rxx:32,ERd COR.U.ERs,ERd XOR.B.Rxx:32,ERd XOR.W.Rxx:16,Rd XOR.W.Rxx:16,Rd XOR.W.Rxx:16,Rd XOR.W.Rs,Rd XOR.W.R	AND	AND.B #xx:8,Rd		2								Rd8∧#xx:8→Rd8	Ι	П	\leftrightarrow	\leftrightarrow	o	,	-
AND.W #xx:16,Rd W 4 AND.W Rs,Rd W 2 AND.L ERS,ERd L 6 AND.L ERS,ERd L 4 OR.B #xx:3,Rd B 2 OR.W #xx:16,Rd W 4 OR.W Rs,Rd W 2 OR.U #xx:32,ERd L 6 OR.U #xx:32,ERd L 6 OR.U #xx:32,ERd L 6 XOR.B #xx:8,Rd B 2 XOR.B Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.U #xx:32,ERd L 6 XO		AND.B Rs,Rd	В	- 1	7							Rd8∧Rs8→Rd8	Ι	П	\leftrightarrow	\leftrightarrow	0	,	
AND.W.Rs,Rd AND.L #xx:32,ERd L 6 AND.L ERs,ERd OR.B #xx:8,Rd OR.B Rs,Rd OR.W Rx,16,Rd OR.W Rs,Rd OR.W Rs,Rd OR.U #xx:32,ERd OR.U #xx:32,ERd OR.U Frs,ERd OR.U Frs,ERd OR.U Frs,ERd OR.U Frs,ERd XOR.B #xx:8,Rd XOR.B #xx:6,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.W Rs,Rd XOR.U #xx:32,ERd XOR.U #xx:32,ERd XOR.U #xx:32,ERd XOR.U Frs,ERd	AND.W #xx:16,Rd		4								Rd16∧#xx:16→Rd16	١	Ι	\leftrightarrow	\leftrightarrow	0	. 7	2	
AND.L #xx:32,ERd		AND.W Rs,Rd	>		2							Rd16∧Rs16→Rd16	I	I	\leftrightarrow	\leftrightarrow	o	,	-
AND.L ERS,ERd L 4 OR.B #xx:8,Rd B 2 OR.W #xx:16,Rd W 4 OR.W #xx:32,ERd L 6 OR.L #xx:32,ERd L 4 OR.L ERS,ERd L 4 XOR.B #xx:8,Rd B 2 XOR.W #xx:16,Rd W 2 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L #xx:32,ERd L 6 XOR.L #xx:32,ERd L 6 XOR.L #xx:32,ERd L 6 NOT.B Rd B 2 NOT.W Rd W 2		AND.L #xx:32,ERd		9								ERd32∧#xx:32→ERd32	Ι	Т	\leftrightarrow	\leftrightarrow	_ o	-	3
OR.B #xx:8,Rd B 2 OR.B Rs,Rd W 4 OR.W Rs,Rd W 2 OR.L #xx:32,ERd L 6 OR.L ERs,ERd L 4 XOR.B #xx:8,Rd B 2 XOR.B Rs,Rd W 4 XOR.W #xx:16,Rd W 2 XOR.W Rs,Rd L 6 XOR.L #xx:32,ERd L 6 XOR.L ERs,ERd L 6 XOR.L ERS,ERd L 6 NOT.B Rd B 2 NOT.W Rd W 2		AND.L ERS,ERd	Г	_	4							ERd32∧ERs32→ERd32		Т	\leftrightarrow	\leftrightarrow	0		2
OR.B Rs,Rd W 4 OR.W #xx:16,Rd W 2 OR.L #xx:32,ERd L 6 OR.L ERS,ERd L 4 XOR.B #xx:3,Rd B 2 XOR.B Rs,Rd B 2 XOR.W #xx:16,Rd W 4 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L ERS,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2	OR	OR.B #xx:8,Rd		7								Rd8∨#xx:8→Rd8	Ι	Т	\leftrightarrow	\leftrightarrow	0	,	
OR.W #xx:16,Rd W 4 OR.W Rs,Rd W 2 OR.L #xx:32,ERd L 4 OR.L ERs,ERd L 4 XOR.B #xx:3,Rd B 2 XOR.W #xx:16,Rd W 4 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L #xx:32,ERd L 6 NOT.B Rd B 2 NOT.W Rd W 2		OR.B Rs,Rd	В	- 1	2							Rd8∨Rs8→Rd8	I	Ι	\leftrightarrow	\leftrightarrow	0	,	
OR.W Rs,Rd W 2 OR.L #xx:32,ERd L 6 OR.L ERS,ERd L 4 XOR.B #xx:8,Rd B 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L ERS,ERd L 6 NOT.B Rd B 2 NOT.W Rd W 2		OR.W #xx:16,Rd		4								Rd16∨#xx:16→Rd16	١	Ι	\leftrightarrow	\leftrightarrow	0		2
OR.L ERS,ERd L 4 OR.L ERS,ERd L 4 XOR.B #xx:8,Rd B 2 XOR.W #xx:16,Rd W 4 XOR.W Rs,Rd W 2 XOR.W Rs,Rd L 6 XOR.L #xx:32,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		OR.W Rs,Rd	≥		7							Rd16∨Rs16→Rd16			\leftrightarrow	\leftrightarrow	<u> </u>	`	_
OR.L ERS, ERd L 4 XOR.B #xx.8,Rd B 2 XOR.W #xx.16,Rd W 4 XOR.W Rs,Rd W 2 XOR.L #xx.32,ERd L 6 XOR.L ERS,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		OR.L #xx:32,ERd		9								ERd32√#xx:32→ERd32	I	ı	\leftrightarrow	\leftrightarrow	0		3
XOR.B #xx:8,Rd B 2 XOR.B Rs,Rd W 4 XOR.W #xx:16,Rd W 2 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L ERs,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		OR.L ERS,ERd	_		4							ERd32∨ERs32→ERd32	I	П	\leftrightarrow	\leftrightarrow	0	-	2
XOR.B Rs,Rd B 2 XOR.W #xx:16,Rd W 4 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L ERS,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2	XOR	XOR.B #xx:8,Rd	В	7								Rd8⊕#xx:8→Rd8	Ι	Т	\leftrightarrow	\leftrightarrow	0	ì	_
XOR.W #xx:16,Rd W 4 XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L ERS,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		XOR.B Rs,Rd	В	•	7							Rd8⊕Rs8→Rd8	I	1	\leftrightarrow	\leftrightarrow	0	,	_
XOR.W Rs,Rd W 2 XOR.L #xx:32,ERd L 6 XOR.L ERs,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		XOR.W #xx:16,Rd		4								Rd16⊕#xx:16→Rd16	I	1	\leftrightarrow	\leftrightarrow	0		2
XOR.L #xx:32,ERd L 6 XOR.L ERS,ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		XOR.W Rs,Rd	≥	· •	2							Rd16⊕Rs16→Rd16	I	1	\leftrightarrow	\leftrightarrow	0	,	_
XOR.L ERS, ERd L 4 NOT.B Rd B 2 NOT.W Rd W 2		XOR.L #xx:32,ERd		9								ERd32⊕#xx:32→ERd32	I	ı	\leftrightarrow	\leftrightarrow	0		3
NOT.B Rd W 2 2 W 2 2 W 2 2 W 2 2 W 2 2 W 2 2 W 2 3 W 2 3 W 3 2 W 3 W 3		XOR.L ERS,ERd	_		4							ERd32⊕ERs32→ERd32	I	П	\leftrightarrow	\leftrightarrow	0	-	2
W 8	NOT	NOT.B Rd	В		7							¬ Rd8→Rd8	Ι	П	\leftrightarrow	\leftrightarrow	0	Ì	_
		NOT.W Rd	>		2							¬ Rd16→Rd16		ı	\leftrightarrow	\leftrightarrow	_ 0		1
NOT.L ERd L 2 ¬ ERd32→ERd32		NOT.L ERd	_		2							¬ ERd32→ERd32	Ī	-	\leftrightarrow	\leftrightarrow	0	,	_

(4) Shift Instructions

			Addressing Mode/ Instruction Length (Bytes)	Add	ress on L	Addressing Mode/ ruction Length (By	Mod th (E	e/ 3yte:	<u>&</u>						
		erand Size	,	นษา	d,ERn)	a ERn/@ERn+	, ()90,b	999				Condition Code	ion C	ode	No. of States*1
	Mnemonic		WXX#			-@ @9			_	Operation		I -	Z	ပ >	Advanced
SHAL	SHAL.B Rd	В	2									<	\leftrightarrow	\leftrightarrow	1
	SHAL.B #2,Rd	В	7										\leftrightarrow	\leftrightarrow	-
	SHAL.W Rd	>	7							Y	0		\leftrightarrow	\leftrightarrow	-
	SHAL.W #2,Rd	>	2						_	C MSB ▲ LSB			\leftrightarrow	\leftrightarrow	-
	SHAL.L ERd	_	2										\leftrightarrow	\leftrightarrow	1
	SHAL.L #2,ERd	_	2									→	\leftrightarrow	\leftrightarrow	1
SHAR	SHAR.B Rd	В	2										\leftrightarrow	↔ 0	1
	SHAR.B #2,Rd	В	2									↔	\leftrightarrow	♦ 0	1
	SHAR.W Rd	8	2								_	<	\leftrightarrow	♦ 0	1
	SHAR.W #2,Rd	×	2							MSB LSB			\leftrightarrow	♦ 0	1
	SHAR.L ERd	Γ	2									<	\leftrightarrow	\$ 0	1
	SHAR.L #2,ERd	_	7									 	\leftrightarrow	 	1
TTHS	SHLL.B Rd	В	2									→	\leftrightarrow	\$ 0	1
	SHLL.B #2,Rd	В	7									<> 	\leftrightarrow	 	1
	SHLL.W Rd	>	7							•	0	<> 	\leftrightarrow	↔ 0	1
	SHLL.W #2,Rd	>	7						_	C MSB ← LSB	'	<> 	\leftrightarrow	<> 0	1
	SHLL.L ERd	_	7								'	<> 	\leftrightarrow	<> 0	1
	SHLL.L #2,ERd	_	7	\Box	\dashv	\dashv	_		\dashv			<> 	\leftrightarrow	<> 0	-

			nstr	Addressing Mode/ Instruction Length (Bytes)	res	sing Len	g‡§ B	g de	(sex								
		eziS bner		Вп	(nЯ∃,t	+uA∃@/uA∃) aa 1,PC)	nne				ndit	ion	Condition Code		No. of States*¹
	Mnemonic	odO xx#	Rn Rn	3@	(c)		שני @9		_	Operation		_	I	N	>	ပ	Advanced
SHLR	SHLR.B Rd	В	2									İ	 	↔	0	\leftrightarrow	_
	SHLR.B #2,Rd	В	7									İ		↔ 0	0	\leftrightarrow	_
	SHLR.W Rd	8	7									İ		⇔ 0	0	\leftrightarrow	_
	SHLR.W #2,Rd	Μ	2							MSB ——— LSB	ပ	İ	 	♦ 0	0	\leftrightarrow	1
	SHLR.L ERd	_	2									İ	1	↔ 0	0	\leftrightarrow	1
	SHLR.L #2,ERd	٦	2									İ	<u> </u>	♦ 0	0	\leftrightarrow	1
ROTXL	ROTXL.B Rd	В	2									İ	1	\leftrightarrow	0	\leftrightarrow	1
	ROTXL.B #2,Rd	В	2									İ	1	\leftrightarrow	0	\leftrightarrow	1
	ROTXL.W Rd	8	2									İ	\7	\leftrightarrow	0	\leftrightarrow	_
	ROTXL.W #2,Rd	M	2							C MSB + LSB	<u>'</u>	İ	\7	\updownarrow	0	\leftrightarrow	1
	ROTXL.L ERd	7	2)	1	İ		\downarrow	0	\leftrightarrow	1
	ROTXL.L #2,ERd	٦	2									İ	1	\leftrightarrow	0	\leftrightarrow	1
ROTXR	ROTXR.B Rd	В	7									İ	\7	\leftrightarrow	0	\leftrightarrow	_
	ROTXR.B #2,Rd	В	2								Г	İ	1	\leftrightarrow	0	\leftrightarrow	1
	ROTXR.W Rd	M	2							<u> </u>	_	Η̈́	\7	\updownarrow	0	\leftrightarrow	1
	ROTXR.W #2,Rd	8	2							MSB TSB C] ()	İ	1	\updownarrow	0	\leftrightarrow	1
	ROTXR.L ERd	٦	2									İ	1	\leftrightarrow	0	\leftrightarrow	1
	ROTXR.L #2,ERd		7			\dashv						İ	\7	\leftrightarrow	0	\leftrightarrow	-

			Insti	Add	ress ion L	Addressing Mode/ Instruction Length (Bytes)	Mod th (E	3yte	(\$)			
		erand Size	,	u N	d,ERn)	-ERn/@ERn+	d,PC)	999			Condition Code	No. of States*¹
	Mnemonic		KX#			@ @			_	Operation	I H N Z V C	Advanced
ROTL	ROTL.B Rd	В	2									1
	ROTL.B #2,Rd	В	2									1
	ROTL.W Rd	8	2							•		1
	ROTL.W #2,Rd	8	2							C MSB • LSB		1
	ROTL.L ERd	٦	2									1
	ROTL.L #2,ERd	Г	2									1
ROTR	ROTR.B Rd	В	7									1
	ROTR.B #2,Rd	В	7								↔ 0 ↔ ⊢ ⊢	-
	ROTR.W Rd	≥	7								↔ 0 ↔ ⊢ ⊢ ⊢	-
	ROTR.W #2,Rd	≥	7							MSB TSB C	↔ 0 ↔ ⊢ ⊢ ⊢	-
	ROTR.L ERd	_	7								↔ 0 ↔ ⊢ – – –	-
	ROTR.L #2,ERd	_	2									1

(5) Bit-Manipulation Instructions

			Inst	Adi	dres tion	sin Ler	Addressing Mode/ Instruction Length (Bytes)	g	/ /tes									
		erand Size		นษา	n,ERn)	ERn/@ERn+	9	(Ja'p				<u> </u>	<u>o</u>	ditio	Š	Condition Code		No. of States*⁴
	Mnemonic		XX#	Rn ⊚E			@ 9) (D)	_	Operation	-	I	z	Z	>	ပ	Advanced
BSET	BSET #xx:3,Rd	В	``	2						#	(#xx:3 of Rd8)←1				I			-
	BSET #xx:3,@ERd	В		4						#)	(#xx:3 of @ERd)←1					<u> </u>	Τ	4
	BSET #xx:3,@aa:8	В					4			#)	(#xx:3 of @aa:8)←1			-		<u> </u>	\neg	4
	BSET #xx:3,@aa:16	В					9			(#)	(#xx:3 of @aa:16)←1		-	-			I	2
	BSET #xx:3,@aa:32	В					8			(#)	(#xx:3 of @aa:32)←1		-	-			I	9
	BSET Rn,Rd	В	.,	2						<u>R</u>	(Rn8 of Rd8)←1			-			-	1
	BSET Rn,@ERd	В		4						<u>R</u>	(Rn8 of @ERd)←1						Ι	4
	BSET Rn,@aa:8	В					4			<u>R</u>	(Rn8 of @aa:8)←1					<u> </u>	Τ	4
	BSET Rn,@aa:16	В					9			<u>R</u>	(Rn8 of @aa:16)←1			Ι		$\frac{1}{1}$	\dashv	2
	BSET Rn,@aa:32	В					8			<u>R</u>	(Rn8 of @aa:32)←1		-	-			I	9
BCLR	BCLR #xx:3,Rd	В	.,	2						#)	(#xx:3 of Rd8)←0		Ш	Ι				_
	BCLR #xx:3,@ERd	В		4						#)	(#xx:3 of @ERd)←0						Ι	4
	BCLR #xx:3,@aa:8	В					4			(#)	(#xx:3 of @aa:8)←0						Ι	4
	BCLR #xx:3,@aa:16	В					9			#)	(#xx:3 of @aa:16)←0					<u> </u>	Т	5
	BCLR #xx:3,@aa:32	В					8			#)	(#xx:3 of @aa:32)←0			Ι		$\frac{\cdot}{1}$	\dashv	9
	BCLR Rn,Rd	В	.,	7						<u>R</u>	(Rn8 of Rd8)←0			Т		1	\dashv	-
	BCLR Rn, @ERd	В		4						<u>R</u>	(Rn8 of @ERd)←0			1				4
	BCLR Rn, @aa:8	В					4			<u>R</u>	(Rn8 of @aa:8)←0	-	1	I	I			4
	BCLR Rn, @aa:16	В	\dashv	\dashv	\dashv		9	\dashv		<u>R</u>	(Rn8 of @aa:16)←0			1		$\frac{1}{1}$	\dashv	2

		ŀ								ŀ		1		ŀ		_
			Inst	Addressing Mode/ Instruction Length (Bytes)	dre	ssin Le	Addressing Mode/ ruction Length (By	oge (B	z g	(s						
		erand Size	;	u Ŋ:	d,ERn)	ERn/@ERn+		(Ja'p	999		Condition Code	e o	Cod	Φ	No. of States*¹	
	Mnemonic		XX#	wE Wu			@ 9		00	_	Operation I H N	7	>	ပ	Advanced	
BCLR	BCLR Rn,@aa:32	В					∞				(Rn8 of @aa:32)←0			1	9	
BNOT	BNOT #xx:3,Rd	В	- "	7							(#xx:3 of Rd8)←[¬ (#xx:3 of Rd8)] — — —			1	1	
	BNOT #xx:3,@ERd	В		4							(#xx:3 of @ERd)←		1	1	4	
											[¬ (#xx:3 of @ERd)]					
	BNOT #xx:3,@aa:8	В					4				(#xx:3 of @aa:8)←				4	
											[¬ (#xx:3 of @aa:8)]					
	BNOT #xx:3,@aa:16	В					9				(#xx:3 of @aa:16)←		1	ı	5	
											[¬ (#xx:3 of @aa:16)]					
	BNOT #xx:3,@aa:32	В					8				(#xx:3 of @aa:32)←			1	9	
											[¬ (#xx:3 of @aa:32)]					
	BNOT Rn,Rd	В	. 4	2							(Rn8 of Rd8)←[¬ (Rn8 of Rd8)]			-	1	
	BNOT Rn, @ERd	В		4							(Rn8 of @ERd)←[¬ (Rn8 of @ERd)] — — —			1	4	
	BNOT Rn, @aa:8	В					4				(Rn8 of @aa:8)←[¬ (Rn8 of @aa:8)] — — — —			1	4	
	BNOT Rn, @aa:16	В					9				(Rn8 of @aa:16)←			1	5	
											[¬ (Rn8 of @aa:16)]					
	BNOT Rn, @aa:32	В					8				(Rn8 of @aa:32)←			1	9	
											[¬ (Rn8 of @aa:32)]					
BTST	BTST #xx:3,Rd	В	٠,٨	7							¬ (#xx:3 of Rd8)→Z	\leftrightarrow		П	1	
	BTST #xx:3,@ERd	В		4							¬ (#xx:3 of @ERd)→Z	\leftrightarrow		Π	3	
	BTST #xx:3,@aa:8	В					4				¬ (#xx:3 of @aa:8)→Z	\leftrightarrow		Т	3	
	BTST #xx:3,@aa:16	В					9				¬ (#xx:3 of @aa:16)→Z	\leftrightarrow			4	
			l		-											

		ŀ				l			ľ			ľ	
			Inst	Addressing Mode/ Instruction Length (Bytes)	Addressing Mode/ ruction Length (By	sing Len	Mo. gth (de/ Byte	es)				
		erand Size		uЯ	(nЯ∃,t	EKn/@EKn+) 1,PC)			Condition Code	Sode	No. of States∗¹
	Mnemonic		XX#	®E Ku			שני @9		_	Operation	N H	ပ >	Advanced
BTST	BTST #xx:3,@aa:32	В					<u>ω</u>			– (#xx:3 of @aa:32)→Z			5
	BTST Rn,Rd	В		7						¬ (Rn8 of Rd8)→Z			-
	BTST Rn,@ERd	В		4						¬ (Rn8 of @ERd)→Z		1	8
	BTST Rn,@aa:8	В					4			¬ (Rn8 of @aa:8)→Z		1	3
	BTST Rn,@aa:16	В					9			¬ (Rn8 of @aa:16)→Z		1	4
	BTST Rn,@aa:32	В					8			¬ (Rn8 of @aa:32)→Z		1	2
BLD	BLD #xx:3,Rd	В	. 1	2						(#xx:3 of Rd8)→C	 	↔	1
	BLD #xx:3,@ERd	В		4						(#xx:3 of @ERd)→C		<> 	3
	BLD #xx:3,@aa:8	В					4			(#xx:3 of @aa:8)→C		<> 	3
	BLD #xx:3,@aa:16	В					9			(#xx:3 of @aa:16)→C		<> 	4
	BLD #xx:3,@aa:32	В					- &			(#xx:3 of @aa:32)→C		<→ 	2
BILD	BILD #xx:3,Rd	В	- 1	2						¬ (#xx:3 of Rd8)→C		<→ 	-
	BILD #xx:3,@ERd	В		4						¬ (#xx:3 of @ERd)→C		<→ 	8
	BILD #xx:3,@aa:8	В					4			¬ (#xx:3 of @aa:8)→C		↔	3
	BILD #xx:3,@aa:16	В					9			– (#xx:3 of @aa:16)→C		<>	4
	BILD #xx:3,@aa:32	В		\dashv			ω			¬ (#xx:3 of @aa:32)→C		<→ 	5
BST	BST #xx:3,Rd	В	.,	7						C→(#xx:3 of Rd8)		 	1
	BST #xx:3,@ERd	В		4						C→(#xx:3 of @ERd)			4
	BST #xx:3,@aa:8	В					4			C→(#xx:3 of @aa:8)		 	4

			Inst	Ad	dres tion	sin Ler	Addressing Mode/ Instruction Length (Bytes)	de/ (B)	rtes				
		erand Size	,	u Ŋ:	(nЯ∃,b	+uA∃@/uA∃		(Ja'p	999		Condition Code	ope	No. of States*1
	Mnemonic		XX#	w Bu			6.0		ത	Operation	Z N H I	۸ <u>ر</u>	Advanced
BST	BST #xx:3,@aa:16	В					9			C→(#xx:3 of @aa:16)			5
	BST #xx:3,@aa:32	В					8			C→(#xx:3 of @aa:32)		 	9
BIST	BIST #xx:3,Rd	В	•	2						¬ C→(#xx:3 of Rd8)		 	1
	BIST #xx:3,@ERd	В		4						¬ C→(#xx:3 of @ERd)		<u> </u> 	4
	BIST #xx:3,@aa:8	В					4			¬ C→(#xx:3 of @aa:8)		<u> </u>	4
	BIST #xx:3,@aa:16	В					9			¬ C→(#xx:3 of @aa:16)		<u> </u>	5
	BIST #xx:3,@aa:32	В					8			¬ C→(#xx:3 of @aa:32)		<u> </u>	9
BAND	BAND #xx:3,Rd	В	•	2						C∧(#xx:3 of Rd8)→C		\leftrightarrow	1
	BAND #xx:3,@ERd	В		4						C∧(#xx:3 of @ERd)→C		\leftrightarrow	3
	BAND #xx:3,@aa:8	В					4			C∧(#xx:3 of @aa:8)→C		\leftrightarrow	ဇ
	BAND #xx:3,@aa:16	В					9			C∧(#xx:3 of @aa:16)→C		\leftrightarrow	4
	BAND #xx:3,@aa:32	В					8			C∧(#xx:3 of @aa:32)→C		\leftrightarrow	5
BIAND	BIAND #xx:3,Rd	В	•	2						C√[¬ (#xx:3 of Rd8)]→C		\leftrightarrow	1
	BIAND #xx:3,@ERd	В		4						C∧[¬ (#xx:3 of @ERd)]→C		\leftrightarrow	3
	BIAND #xx:3,@aa:8	В					4			C∧[¬ (#xx:3 of @aa:8)]→C		\leftrightarrow	3
	BIAND #xx:3, @aa:16	В					9			C∧[¬ (#xx:3 of @aa:16)]→C	1 1	\leftrightarrow	4
	BIAND #xx:3,@aa:32	В					8			C∧[¬ (#xx:3 of @aa:32)]→C		\leftrightarrow	5
BOR	BOR #xx:3,Rd	В	``	7						C√(#xx:3 of Rd8)→C		\leftrightarrow	1
	BOR #xx:3,@ERd	В	-	4	_	\Box		\dashv	\dashv	C√(#xx:3 of @ERd)→C	 	\leftrightarrow	3

		_	nstr	Add ucti	Addressing Mode/ Instruction Length (Bytes)	ing l	Mod th (E	e/ 3yte	s)				
		erand Size		иЯ	d,ERn)	BRn/@ERn+	(JG,b	999			Condition Code	No. of States*1	**
	Mnemonic		κx#			-@ @			_	Operation	I H N Z V C	Advanced	
BOR	BOR #xx:3,@aa:8	В				4				C√(#xx:3 of @aa:8)→C		3	
	BOR #xx:3,@aa:16	В				9				C√(#xx:3 of @aa:16)→C		4	
	BOR #xx:3, @aa:32	В				∞				C√(#xx:3 of @aa:32)→C		2	
BIOR	BIOR #xx:3,Rd	В	2							C√[¬ (#xx:3 of Rd8)]→C		1	
	BIOR #xx:3,@ERd	В		4						C√[¬ (#xx:3 of @ERd)]→C	→ <p< td=""><td>3</td><td></td></p<>	3	
	BIOR #xx:3,@aa:8	В				4				C√[¬ (#xx:3 of @aa:8)]→C		3	
	BIOR #xx:3,@aa:16	В				9				C√[¬ (#xx:3 of @aa:16)]→C		4	
	BIOR #xx:3,@aa:32	В				8				C√[¬ (#xx:3 of @aa:32)]→C		2	
BXOR	BXOR #xx:3,Rd	В	2							C⊕(#xx:3 of Rd8)→C		1	
	BXOR #xx:3,@ERd	В		4						C⊕(#xx:3 of @ERd)→C		3	
	BXOR #xx:3,@aa:8	В				4				C⊕(#xx:3 of @aa:8)→C	→ — — — — — — — — — — — — —	3	
	BXOR #xx:3,@aa:16	В				9				C⊕(#xx:3 of @aa:16)→C		4	
	BXOR #xx:3,@aa:32	В				8				C⊕(#xx:3 of @aa:32)→C		2	
BIXOR	BIXOR #xx:3,Rd	В	2							C⊕[¬ (#xx:3 of Rd8)]→C		1	
	BIXOR #xx:3,@ERd	В		4						C⊕[¬ (#xx:3 of @ERd)]→C		3	
	BIXOR #xx:3,@aa:8	В				4				C⊕[¬ (#xx:3 of @aa:8)]→C		3	
	BIXOR #xx:3,@aa:16	В				9				C⊕[¬ (#xx:3 of @aa:16)]→C		4	
	BIXOR #xx:3, @aa:32	В	\dashv			- ∞	_		\dashv	C⊕[¬ (#xx:3 of @aa:32)]→C		2	

(6) Branch Instructions

			Instr	Addr	Addressing Mode/ Instruction Length (Bytes)	g Mc ngth	ge/	tes)							
		əzi2 bn		ı	Ru)@ERu+			100	Operation		Cor	Condition Code	S C	opo	No. of States*1
	Mnemonic		HXX	@EBr	a(b)@ 9====================================	@99	പു .b)ത ലെത്ത	<u>—</u> © © 93	_	Branching Condition		z	7	ر >	Advanced
Bcc	BRA d:8(BT d:8)	1					2		if condition is true then	Always					2
	BRA d:16(BT d:16)	1					4		PC←PC+d				Ι	I	3
	BRN d:8(BF d:8)	-					2		else next;	Never			١	I	2
	BRN d:16(BF d:16)	-					4				<u> </u> 			<u> </u>	3
	BHI d:8	-					2			C~Z=0			Ι	 	2
	BHI d:16	-					4				<u> </u> 				3
	BLS d:8	-					2			C∨Z=1	<u> </u> 				2
	BLS d:16	-					4								3
	BCC d:B(BHS d:8)	-					2			C=0			Ι	 	2
	BCC d:16(BHS d:16)	-					4							<u> </u>	3
	BCS d:8(BLO d:8)	-					2			C=1		-	Ι		2
	BCS d:16(BLO d:16)	-					4				<u> </u> 				3
	BNE d:8	-					2			Z=0					2
	BNE d:16	-					4								3
	BEQ d:8						2			Z=1	<u> </u> 				2
	BEQ d:16	I					4				<u> </u>	\perp	-	$\frac{1}{1}$	3
	BVC d:8	I					7			N=0	$\frac{\perp}{\Box}$	+	Τ	$\frac{1}{1}$	2
	BVC d:16	Ι					4				<u> </u>	\dashv		\blacksquare	3

		-	Addressing Mode/ Instruction Length (Bytes)	ddre	Addressing Mode/ ruction Length (By	g Ma	ode/ (Byt	(se)							
		əzi& bri			Kn)@ERn+			n	Operation		Con	dition	Condition Code		No. of States*¹
	Mnemonic		uy #xx	@ERr	3,b)@ 9====================================	@99	(d,F @ @a	_ _		Branching Condition		Z	> Z	C A	Advanced
Bcc	BVS d:8	-					2			V=1	<u> </u>	<u> </u>	-	_	2
	BVS d:16	I					4				<u> </u> 	<u> </u>		_	3
	BPL d:8	I					2			0=N		<u> </u>	-		2
	BPL d:16	-					4				<u> </u> -				3
	BMI d:8	П					2			N=1	\mathbb{H}				2
	BMI d:16	Ι					4				<u> </u>	1		1	3
	BGE d:8	T					7			0=\⊕N					2
	BGE d:16						4				\Box	<u> </u>			3
	BLT d:8	Τ					7			N⊕V=1	<u> </u> 			1	2
	BLT d:16	Ι					4				<u> </u> 				3
	BGT d:8	I					2			Z~(N⊕V)=0					2
	BGT d:16	-					4				<u> </u> -	<u> </u>	<u> </u> 		3
	BLE d:8	Ι					2			Z~(N⊕V)=1	<u> </u>	1			2
	BLE d:16	\exists					4				$\frac{\perp}{\perp}$	<u> </u>			3

			Inst	Add	Addressing Mode/ Instruction Length (Bytes)	ing eng	Mod Th (I	le/ Byte	(S				
		erand Size		L L L	(uA∃ʻr	ERn/@ERn+	(Dd,t	999			Condition Code	No. of States*1	
	Mnemonic		XX#	®E gu	(c)		(G (G (G		_	Operation	> X X H	Advanced	_
JMP	JMP @ERn	1		2						PC←ERn		2	_
	JMP @aa:24					7	4			PC←aa:24		3	
	JMP @ @aa:8	I						2		PC←@aa:8	 	5	
BSR	BSR d:8						7			PC→@-SP,PC←PC+d:8		4	_
	BSR d:16	-					4			PC→@-SP,PC←PC+d:16	 	5	_
JSR	JSR @ERn			2						PC→@-SP,PC←ERn	 	4	_
	JSR @aa:24					7	4			PC→@-SP,PC←aa:24	 	5	
	JSR @@aa:8							2		PC→@-SP,PC←@aa:8		9	
RTS	RTS								7	PC←@SP+	 	5	_

(7) System Control Instructions

				Adc	res	ing	Addressing Mode/	e e								
			Inst	ruct	<u>io</u>	Lenç	Instruction Length (Bytes)	Byte	(S)							
		erand Size		Вn	i,ERn)	ERn/@ERn+	1,PC)	999			<u> </u>	Condition Code	ifi	ပိ	de	No. of States*1
	Mnemonic		XX#	®E gu			(0 (0 (0		_	Operation	_	I	z	7	S	Advanced
TRAPA	TRAPA #xx:2	Ι								PC→@-SP,CCR→@-SP,	-	İ	H		-	8 [9]
										EXR→@-SP, <vector>→PC</vector>						
RTE	RTE	-								EXR←@SP+,CCR←@SP+,	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	[6] 9
									_	PC←@SP+						
SLEEP	SLEEP	Т								Transition to power-down state		İ	H	1	_	2
CDC	LDC #xx:8,CCR	В	2							#xx:8→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	LDC #xx:8,EXR	В	4							#xx:8→EXR	Ī	İ	<u> </u>		- —	2
	LDC Rs,CCR	В	.,	7			_			Rs8→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	1
	LDC Rs, EXR	В	.,	7						Rs8→EXR	Ī	İ	$^{+}$	$^{\perp}$		1
	LDC @ERs,CCR	>		4						@ERs→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	3
	LDC @ERs,EXR	8		4						@ERs→EXR	Ī	İ	<u> </u>	1		3
	LDC @(d:16,ERs),CCR	≥			9					@(d:16,ERs)→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	4
	LDC @(d:16,ERs),EXR	>			9					@(d:16,ERs)→EXR	Ī	İ	1	1	_	4
	LDC @(d:32,ERs),CCR	>			10					@(d:32,ERs)→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	9
	LDC @(d:32,ERs),EXR	>			10					@(d:32,ERs)→EXR		İ	H	1	_	9
	LDC @ERs+,CCR	X				4				@ERs→CCR,ERs32+2→ERs32	\leftrightarrow	\leftrightarrow	\leftrightarrow	$\overset{\leftrightarrow}{\leftrightarrow}$	\leftrightarrow	4
	LDC @ERs+,EXR	>				4				@ERs→EXR,ERs32+2→ERs32	Ī	İ	<u> </u>			4
	LDC @aa:16,CCR	≥					9			@aa:16→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	4
	LDC @aa:16,EXR	>				_	9			@aa:16→EXR	Ī	İ	$\frac{1}{1}$	1	_	4
	LDC @aa:32,CCR	>					8			@aa:32→CCR	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	5
	LDC @aa:32,EXR	>		_		_	- 8			@aa:32→EXR	Ī	İ	$^{+}$	$\frac{\perp}{\Box}$	_	5

			Ins	Addressing Mode/ Instruction Length (Bytes)	ddr	essi	ng eng	Addressing Mode/ ruction Length (By	le/ Byt	es)										
		erand Size			LED ,	d,ERn)	-ERn/@ERn+	d,PC)	@99 c':-c)				ပိ	Condition Code	iti:	S C	Ö	Φ	No. of States*¹	1
	Mnemonic	dΟ	KX#	uЯ)@ 2@		_	Operation		-	I	Z	7	>	ပ	Advanced	
STC	STC CCR,Rd	В		7							CCR→Rd8		Ι	Ī		_		ı	1	
	STC EXR,Rd	В		7							EXR→Rd8		Ι	Ī	ı		1	ı	-	
	STC CCR, @ERd	≥			4						CCR→@ERd		-	Ī	-	-	1	-	3	
	STC EXR, @ERd	≥			4						EXR→@ERd			Ī	-		-		8	
	STC CCR, @ (d:16, ERd)	>				9					CCR→@(d:16,ERd)		Ι	Ī				T	4	
	STC EXR, @(d:16, ERd)	>				9					EXR→@(d:16,ERd)		Ι	Ī				Т	4	
	STC CCR, @ (d:32,ERd)	≥			<u> </u>	10					CCR→@(d:32,ERd)		Ι	Ī	-		-	ı	9	
	STC EXR, @(d:32, ERd)	>			_	10					EXR→@(d:32,ERd)		Ι	Ī				Τ	9	
	STC CCR,@-ERd	Λ				_	4				ERd32-2→ERd32,CCR→@ERd	ERd	Ι	Ī		_	_	-	4	
	STC EXR, @-ERd	>					4				ERd32-2→ERd32,EXR→@ERd	ERd	Τ	Π				Т	4	
	STC CCR,@aa:16	>					٤	9			CCR→@aa:16		Τ	Ī				Τ	4	
	STC EXR,@aa:16	>					٤	9			EXR→@aa:16		Ι	Ī				Τ	4	
	STC CCR,@aa:32	≥					8				CCR→@aa:32		Ι	Τ			-	Τ	5	
	STC EXR, @aa:32	>					8				EXR→@aa:32		Ι	Ī				-	5	
ANDC	ANDC #xx:8,CCR	В	2								CCR∧#xx:8→CCR		\leftrightarrow	\leftrightarrow	\leftrightarrow	\Rightarrow	\leftrightarrow	\leftrightarrow	1	
	ANDC #xx:8,EXR	В	4								EXR∧#xx:8→EXR		Τ	Π				T	2	
ORC	ORC #xx:8,CCR	В	2								CCR∨#xx:8→CCR		\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	1	
	ORC #xx:8,EXR	В	4								EXR∨#xx:8→EXR		Τ				Т	Т	2	
XORC	XORC #xx:8,CCR	В	7				-				CCR⊕#xx:8→CCR		\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	\leftrightarrow	_	
	XORC #xx:8,EXR	В	4								EXR⊕#xx:8→EXR		Τ	Ī			-	T	2	- 1
NOP	NOP	Ι								7	PC←PC+2		Τ	Ι			-	Τ	_	

(8) Block Transfer Instructions

	75								
	No. of States*1	Advanced	4+2n *2						4+2n *²
	e	ပ	Ì						Ì
	Condition Code	N Z V							1
	ion	N							1
	ndir	I	<u> </u>						
	ပိ	_	i						
		Operation	=	Repeat @ER5→@ER6 FP5-1 → FP5	ER6+1→ER6	R4L-1→R4L	Until R4L=0	else next;	if R4≠0 Repeat @ER5→@ER6 ER5+1→ER5 ER6+1→ER6 R4-1→R4 Until R4=0 else next;
Addressing Mode/ Instruction Length (Bytes)	999	<u> </u>	4						4
Addressing Mode/ ruction Length (Byt	(Ja,								
Mo	(90 P	100 100							
ing en	+uŊ∃@/uŊ∃								
ess on I	d,ERn)								
ddr	uЫ								
Str		Вn							
므		XX#							
	erand Size	ďΟ							I
		Mnemonic	EEPMOV.B						EEPMOV.W
			EEPMOV						

The number of states is the number of states required for execution when the instruction and its operands are located in on-chip memory. બ છ Notes:

n is the initial value of R4L or R4.

[1] Seven states for saving or restoring two registers, nine states for three registers, or eleven states for four registers. Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction.

Cannot be used in the H8S/2357 Series.

Set to 1 when a carry or borrow occurs at bit 11; otherwise cleared to 0. 26466689

Retains its previous value when the result is zero; otherwise cleared to 0. Set to 1 when a carry or borrow occurs at bit 27; otherwise cleared to 0.

Set to 1 when the divisor is negative; otherwise cleared to 0.

Set to 1 when the divisor is zero; otherwise cleared to 0.

One additional state is required for execution when EXR is valid. Set to 1 when the quotient is negative; otherwise cleared to 0.

A.2 Instruction Codes

Table A-2 shows the instruction codes.

Table A-2 Instruction Codes

1								Instruction	Instruction Format				
tion	Mnemonic	Size	1st byte	ıyte	2nd byte	3rd byte	4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
ADD	ADD.B #xx:8,Rd	m	80	5	MMI								
	ADD.B Rs,Rd	ш	0	80	r D								
	ADD.W #xx:16,Rd	≥	7	6	٦ ت	IMM	5						
	ADD.W Rs,Rd	8	0	6	rs rd								
	ADD.L #xx:32,ERd	٦	7	A	1 0 erd		IMM	N					
	ADD.L ERS,ERd	٦	0	A	1 ers 0 erd								
ADDS	ADDS #1,ERd	_	0	В	0 0 erd								
	ADDS #2,ERd	_	0	М	8 0 erd								
	ADDS #4,ERd	_	0	В	9 0 erd								
ADDX	ADDX #xx:8,Rd	В	6	rd	IMM								
	ADDX Rs,Rd	В	0	ш	rs rd								
AND	AND.B #xx:8,Rd	В	В	<u>r</u>	IMM								
	AND.B Rs,Rd	В	-	9	rs								
	AND.W #xx:16,Rd	8	7	6	e rd	IMM	N						
	AND.W Rs,Rd	>	9	9	rs rd								
	AND.L #xx:32,ERd	٦	7	A	6 0 erd		IMM	N					
	AND.L ERS,ERd	_	0	1	F 0	9 9	0 ers 0 erd						
ANDC	ANDC #xx:8,CCR	М	0	9	IMM								
	ANDC #xx:8,EXR	В	0	1	1	9 0	IMM						
BAND	BAND #xx:3,Rd	В	7	9	0 IMM rd								
	BAND #xx:3,@ERd	В	7	ပ	0 erd 0	9 /	0 MMI 0						
	BAND #xx:3,@aa:8	В	7	В	abs	9 /	O IMM O						
	BAND #xx:3,@aa:16	В	9	A	1 0	abs	S	9 /	0 IMM 0				
	BAND #xx:3,@aa:32	В	9	∢	3 0		abs	s		9 /	0 IMM 0		
Всс	BRA d:8 (BT d:8)	I	4	0	dsib								
	BRA d:16 (BT d:16)	I	2	8	0 0	disb	ф						
	BRN d:8 (BF d:8)	I	4	1	dsip								
	BRN d:16 (BF d:16)	I	2	8	1 0	disp	р						

Instruc-	Momoria	-						Instruction Format	n Format				
tion		Size		1st byte	2nd byte	3rd byte	4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
Bcc	BHI d:8	Ī	4	2	disp								
	BHI d:16	I	2	8	2 0	disp	d.						
	BLS d:8	Ι	4	3	dsib								
	BLS d:16	I	2	8	3 0	dsib	d						
	BCC d:8 (BHS d:8)	Ī	4	4	dsip								
	BCC d:16 (BHS d:16)	Ī	9	8	4 0	dsib	d						
	BCS d:8 (BLO d:8)		4	2	dsib								
	BCS d:16 (BLO d:16)	Ī	9	8	2 0	dsib	d						
	BNE d:8	I	4	9	dsip								
	BNE d:16	Ī	9	8	0 9	disp	d						
	BEQ d:8	I	4	7	dsip								
	BEQ d:16	Ī	9	8	0 2	dsib	d						
	BVC d:8	Ī	4	8	dsip								
	BVC d:16	I	9	8	0 8	dsib	dt						
	BVS d:8	Ī	4	6	dsip								
	BVS d:16	I	9	8	0 6	dsib	d						
	BPL d:8	Ī	4	A	dsip								
	BPL d:16	Ī	2	8	0 Y	disp	d.						
	BMI d:8		4	В	dsib								
	BMI d:16	Ī	2	8	D 0	dsip	d						
	BGE d:8	Ī	4	၁	dsip								
	BGE d:16	Ī	2	8	C 0	disp	d						
	BLT d:8		4	۵	dsib								
	BLT d:16	Ι	2	8	0 0	disp	Q						
	BGT d:8	Ι	4	ш	dsib								
	BGT d:16	Ι	2	8	Е 0	disp	Q						
	BLE d:8	I	4	ш	dsib								
	BLE d:16	Ι	2	8	0	dsib	ą.						

Instruc-	Mnemonic	ë							Instruction	Instruction Format				
tion		Size	1st byte	yte	2nd byte	byte	3rd byte	4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
BCLR	BCLR #xx:3,Rd	В	7	2	имі о	rd								
	BCLR #xx:3,@ERd	В	7	D	0 erd	0	7 2	0 MMI 0						
	BCLR #xx:3,@aa:8	В	7	ь	abs	S	7 2	O MMI O						
	BCLR #xx:3,@aa:16	В	9	A	-	8	abs	S	7 2	0 MMI 0				
	BCLR #xx:3, @aa:32	В	9	A	3	8		ā	abs		7 2	0 MMI 0		
	BCLR Rn,Rd	В	9	2	٤	rd								
	BCLR Rn, @ERd	В	7	۵	0 erd	0	6 2	0						
	BCLR Rn, @aa:8	В	7	ч	abs	S	6 2	n 0						
	BCLR Rn,@aa:16	В	9	A	-	8	abs	S	6 2	rn 0				
	BCLR Rn,@aa:32	В	9	Α	3	8		ä	abs		6 2	rn 0		
BIAND	BIAND #xx:3,Rd	В	7	9	1 IMM	rd								
	BIAND #xx:3,@ERd	В	7	၁	0 erd	0	9 /	1 IMM 0						
	BIAND #xx:3, @aa:8	В	7	Е	abs	Sc	9 /	1 IMM 0						
	BIAND #xx:3,@aa:16	В	9	A	-	0	abs	S	9 /	1 IMM 0				
	BIAND #xx:3, @aa:32	В	9	Α	3	0		ä	abs		9 /	1 IMM 0		
BILD	BILD #xx:3,Rd	В	7	7	1 IMM	rd								
	BILD #xx:3,@ERd	В	7	ပ	0 erd	0	7 7	1 IMM 0						
	BILD #xx:3,@aa:8	В	7	ш	aps	S	7 7	1 IMM 0						
	BILD #xx:3,@aa:16	В	9	Α	-	0	abs	S	7 7	1 IMM 0				
	BILD #xx:3,@aa:32	В	9	Α	3	0		ä	abs		7 7	1 IMM 0		
BIOR	BIOR #xx:3,Rd	В	7	4	1 IMM	ы								
	BIOR #xx:3, @ERd	В	7	ပ	0 erd	0	7 4	1 IMM 0						
	BIOR #xx:3, @aa:8	В	7	Е	abs	S	7 4	1 IMM 0						
	BIOR #xx:3,@aa:16	В	9	۷	τ-	0	abs	S	7 4	1 IMM 0				
	BIOR #xx:3,@aa:32	В	9	∢	3	0		ซ	abs		7 4	1 IMM 0		

Instruc-	, in our M									Instr	uction	Instruction Format				
tion		Size		1st byte	2nd byte	yte	3rd byte	_	4th byte	5th byte	rte	6th byte	7th byte	8th byte	9th byte	10th byte
BIST	BIST #xx:3,Rd	В	9	7	1 IMM	rd										
	BIST #xx:3,@ERd	В	7	О	0 erd	0	9	7 1	1 IMM 0							
	BIST #xx:3,@aa:8	В	7	ч	abs	s	9	7 1	1 IMM 0							
	BIST #xx:3,@aa:16	В	9	A	1	8		abs		9	7 1	1 IMM 0				
	BIST #xx:3,@aa:32	В	9	٨	က	ω				abs			2 9	1 IMM 0		
BIXOR	BIXOR #xx:3,Rd	В	7	2	1 IMM	rd										
	BIXOR #xx:3,@ERd	В	7	ပ	0 erd	0	3 /	5 1	1 IMM 0							
	BIXOR #xx:3,@aa:8	В	7	Ш	aps	S	3 /	5 1	1 IMM 0							
	BIXOR #xx:3,@aa:16	В	9	A	1	0		abs		7	5 1	1 IMM 0				
	BIXOR #xx:3,@aa:32	В	9	Α	3	0				abs			7 5	1 IMM 0		
BLD	BLD #xx:3,Rd	В	7	7	имі о	гд										
	BLD #xx:3,@ERd	В	7	ပ	0 erd	0	7	7 0	0 IMM 0							
	BLD #xx:3,@aa:8	В	7	ш	abs	s	7 7	7 0	0 MMI 0							
	BLD #xx:3,@aa:16	В	9	A	1	0		aps		7	7 0	0 MMI 0				
	BLD #xx:3,@aa:32	В	9	Α	3	0				abs			7 7	O IMM O		
BNOT	BNOT #xx:3,Rd	В	7	-	имі о	rd										
	BNOT #xx:3,@ERd	В	7	٥	0 erd	0	7	1 0	0 MMI 0							
	BNOT #xx:3,@aa:8	В	7	ш	abs	s	7	1	0 IMM 0							
	BNOT #xx:3,@aa:16	В	9	A	1	8		abs		7	1 6	0 ммі 0				
	BNOT #xx:3,@aa:32	В	9	A	3	8				abs			7 1	0 MMI 0		
	BNOT Rn,Rd	В	9	-	u	rd										
	BNOT Rn, @ ERd	В	7	۵	0 erd	0	9	_	m 0							
	BNOT Rn,@aa:8	В	7	ч	abs	s	9		n 0							
	BNOT Rn,@aa:16	М	9	⋖	-	80		aps		9	_	0				
	BNOT Rn,@aa:32	В	9	4	က	80				abs			6 1	rn 0		

Instruc-	Mnemonic	ا							ü	structio	Instruction Format				
tion		2170	1st	1st byte	2nd byte	oyte	3rd byte	4th byte		5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
BOR	BOR #xx:3,Rd	В	7	4	о імм	rd									
	BOR #xx:3,@ERd	В	7	ပ	0 erd	0	7 4	0 IMM 0							
	BOR #xx:3,@aa:8	М	7	ш	aps	S	7 4	0 IMMI 0							
	BOR #xx:3,@aa:16	В	9	∢	1	0		abs	7	4	0 IMMI 0				
	BOR #xx:3,@aa:32	В	9	٨	3	0			abs			7 4	0 IMM 0		
BSET	BSET #xx:3,Rd	В	7	0	о імм	rd									
	BSET #xx:3,@ERd	ш	7	۵	0 erd	0	7 0	0 IMM 0							
	BSET #xx:3,@aa:8	Ф	7	ட	aps	õ	7 0	0 MMI 0							
	BSET #xx:3,@aa:16	В	9	∢	1	8		abs	7	0	O IMM O				
	BSET #xx:3,@aa:32	В	9	∢	3	8			abs			7 0	0 IMM 0		
	BSET Rn,Rd	В	9	0	Ľ	rd									
	BSET Rn, @ERd	В	7	۵	0 erd	0	0 9	rn 0							
	BSET Rn, @aa:8	В	7	ш	abs	S	0 9	0							
	BSET Rn,@aa:16	В	9	∢	1	8		abs	9	0	rn 0				
	BSET Rn, @aa:32	В	9	∢	က	8			abs			0 9	0		
BSR	BSR d:8	I	2	2	dsib	ds									
	BSR d:16	I	5	၁	0	0	,	disp							
BST	BST #xx:3,Rd	В	9	7	о імм	rd									
	BST #xx:3,@ERd	В	7	۵	0 erd	0	2 9	0 IMM 0							
	BST #xx:3,@aa:8	В	7	ш	abs	S	2 9	0 IMM 0							
	BST #xx:3,@aa:16	В	9	⋖	1	8		abs	9	7	0 IMM 0				
	BST #xx:3,@aa:32	В	9	A	3	8			abs			6 7	0 IMM 0		
втѕт	BTST #xx:3,Rd	В	7	3	о імм	rd									
	BTST #xx:3,@ERd	В	7	ပ	0 erd	0	7 3	0 IMM 0							
	BTST #xx:3,@aa:8	М	7	ш	aps	S	7 3	0 IMM 0							
	BTST #xx:3,@aa:16	М	9	∢	-	0		abs	7	3	0 IMM 0				
	BTST #xx:3,@aa:32	В	9	۷	3	0			aps			7 3	0 IMM 0		
	BTST Rn,Rd	В	9	3	Ľ	rd									
	BTST Rn,@ERd	В	7	ပ	0 erd	0	6 3	0 LL							

Instruc-	di se di se di se di se di se di se di se di se di se di se di se di se di se di se di se di se di se di se di									Instruct	Instruction Format				
tion	Minemoric	Size		1st byte	2nd byte	oyte	3rd byte		4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
BTST	BTST Rn,@aa:8	В	7	ш	abs	s	9	ıı	0						
	BTST Rn,@aa:16	В	9	4	-	0		abs		6 3	rn 0				
	BTST Rn,@aa:32	В	9	٨	3	0			w	abs		6 3	rn 0		
BXOR	BXOR #xx:3,Rd	В	7	2	о імм	rd									
	BXOR #xx:3,@ERd	В	7	ပ	0 erd	0	7 5	O IMM	0						
	BXOR #xx:3,@aa:8	В	7	ш	abs	S	7 5	OIMM	0						
	BXOR #xx:3,@aa:16	М	9	∢	~	0		aps		7 5	0 MMI 0				
	BXOR #xx:3,@aa:32	М	9	∢	က	0			ω	abs		7 5	0 MMI 0		
CLRMAC CLRMAC	CLRMAC	Ι	Can	not be	used in	the H85	Cannot be used in the H8S/2357 Series	ries							
CMP	CMP.B #xx:8,Rd	В	٧	p	IMM	>									
	CMP.B Rs,Rd	В	-	ပ	ร	<u>r</u>									
	CMP.W #xx:16,Rd	>	7	6	2	<u>r</u>		IMM							
	CMP.W Rs,Rd	≥	_	۵	হ	Þ									
	CMP.L #xx:32,ERd	_	7	A	2	0 erd			=	IMM					
	CMP.L ERS,ERd	L	1	н	1 ers (0 erd									
DAA	DAA Rd	В	0	Н	0	rd									
DAS	DAS Rd	В	1	Н	0	rd									
DEC	DEC.B Rd	В	1	A	0	rd									
	DEC.W #1,Rd	8	-	В	2	rd									
	DEC.W #2,Rd	×	1	В	۵	rd									
	DEC.L #1,ERd	٦	-	М		0 erd									
	DEC.L #2,ERd	L	1	В	Ь	0 erd									
DIVXS	DIVXS.B Rs,Rd	В	0	1	۵	0	5 1	rs	rq						
	DIVXS.W Rs,ERd	M	0	-	D	0	5 3	rs	0 erd						
DIVXU	DIVXU.B Rs,Rd	В	2	1	rs	rd									
	DIVXU.W Rs,ERd	8	2	3	LS	0 erd									
EEPMOV	EEPMOV EEPMOV.B	Ι	7	В	2	C	6 9	8	ъ						
	EEPMOV.W	I	7	а	۵	4	5	8	ъ.						

Instruc-	Magazic	ä							Instru	Instruction Format	mat				
tion		Size	1st	1st byte	2nd	2nd byte	3rd byte	4th byte	5th byte		6th byte	7th byte	8th byte	9th byte	10th byte
EXTS	EXTS.W Rd	>	-	7	۵	5									
	EXTS.L ERd	Г	1	7	ч	0 erd									
EXTU	EXTU.W Rd	M	1	7	2	r									
	EXTU.L ERd	Г	1	7	7	0 erd									
INC	INC.B Rd	В	0	٧	0	5									
	INC.W #1,Rd	≥	0	В	2	5									
	INC.W #2,Rd	≥	0	В	۵	5									
	INC.L #1,ERd	_	0	В	7	0 erd									
	INC.L #2,ERd	٦	0	В	ь	0 erd									
JMP	JMP @ERn	Ι	2	6	0 ern	0									
	JMP @aa:24	Ι	5	Α			abs								
	JMP @@aa:8	Ι	5	В	ā	abs									
JSR	JSR @ERn	I	2	О	0 ern	0									
	JSR @aa:24	Ι	5	Е			abs								
	JSR @@aa:8	Ι	5	F	a	abs									
ГРС	LDC #xx:8,CCR	В	0	7	NI.	IMM									
	LDC #xx:8,EXR	В	0	1	4	1	0 7	IMM							
	LDC Rs,CCR	В	0	3	0	S									
	LDC Rs,EXR	В	0	3	1	S									
	LDC @ERs,CCR	≥	0	1	4	0	6 9	0 ers 0							
	LDC @ERs,EXR	≥	0	1	4	-	6 9	0 ers 0							
	LDC @(d:16,ERs),CCR	≥	0	1	4	0	9	0 ers 0		disp					
	LDC @(d:16,ERs),EXR	≥	0	-	4	-	9	0 ers 0		disb					
	LDC @(d:32,ERs),CCR	≥	0	1	4	0	7 8	0 ers 0	9	B 2	0		di	dsip	
	LDC @(d:32,ERs),EXR	≥	0	1	4	-	7 8	0 ers 0	9	B 2	0		dis	disp	
	LDC @ERs+,CCR	≥	0	-	4	0	О 9	0 ers 0							
	LDC @ERs+,EXR	≥	0	1	4	-	О 9	0 ers 0							
	LDC @aa:16,CCR	8	0	1	4	0	6 B	0 0		disp					
	LDC @aa:16,EXR	>	0	-	4	-	6 B	0 0		disp					

notrio											Instruction Format	n Format				
tion	Mnemonic	Size		1st byte	2nd byte	byte	3rd byte	yte	4th byte	yte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
ГРС	LDC @aa:32,CCR	Μ	0	-	4	0	9	В	2	0		at	abs			
	LDC @aa:32,EXR	8	0	-	4	-	9	В	2	0		at	abs			
ПБМ	LDM.L @SP+, (ERn-ERn+1)	٦	0	-	1	0	9	D	7	0 em+1						
	LDM.L @SP+, (ERn-ERn+2)	٦	0	-	2	0	9	٥	7	0 em+2						
	LDM.L @SP+, (ERn-ERn+3)	_	0	-	3	0	9	D	7	0 em+3						
LDMAC	LDMAC LDMAC ERS,MACH	_	Can	not be	Cannot be used in the H8S/2357 Series	the H8	S/2357	Series	,							
	LDMAC ERS,MACL	_														
MAC	MAC @ERn+,@ERm+	Ī														
MOV	MOV.B #xx:8,Rd	В	Ь	Б	MMI	Σ										
	MOV.B Rs,Rd	В	0	ပ	LS.	<u>r</u>										
	MOV.B @ERs,Rd	В	9	8	0 ers	<u>r</u>										
	MOV.B @(d:16,ERs),Rd	В	9	ш	0 ers	rd		disp	ď							
	MOV.B @(d:32,ERs),Rd	В	2	8	0 ers	0	9	A	2	p		di	disp			
	MOV.B @ERs+,Rd	В	9	ပ	0 ers	ū										
	MOV.B @aa:8,Rd	В	2	5	abs	SC										
	MOV.B @aa:16,Rd	В	9	⋖	0	Б		aps	ş							
	MOV.B @aa:32,Rd	В	9	⋖	2	Б				aps	s					
	MOV.B Rs,@ERd	В	9	8	1 erd	rs										
	MOV.B Rs, @ (d:16,ERd)	В	9	ш	1 erd	S		disp	ď							
	MOV.B Rs, @ (d:32,ERd)	В	7	80	0 erd	0	9	4	∢	rs.		di	disp			
	MOV.B Rs,@-ERd	В	9	ပ	1 erd	S										
	MOV.B Rs,@aa:8	В	3	ទ	aps	SC										
	MOV.B Rs,@aa:16	В	9	∢	8	rs		abs	S							
	MOV.B Rs,@aa:32	В	9	∢	A	rs				abs	S					
	MOV.W #xx:16,Rd	M	2	6	0	rd		IMM	Σ							
	MOV.W Rs,Rd	M	0	۵	rs	rd										
	MOV.W @ERs,Rd	M	9	6	0 ers	rd										
	MOV.W @(d:16,ERs),Rd	8	9	ш	0 ers	ī		dsib	dć							
	MOV.W @ (d:32,ERs),Rd	8	7	ھ	0 ers	0	9	В	2	ī.		dj	disp			

Instruc-	Momorio	7							Instruction	Instruction Format				
tion		Size	1st byte) yte	2nd	2nd byte	3rd byte	4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
MOV	MOV.W @ERs+,Rd	M	9	D	0 ers	rd								
	MOV.W @aa:16,Rd	8	9	В	0	rd	al	abs						
	MOV.W @aa:32,Rd	8	9	В	2	rd		B	abs					
	MOV.W Rs,@ERd	8	9	6	1 erd	ទ								
	MOV.W Rs, @ (d:16,ERd)	8	9	ь	1 erd	rs	ğ	dsib						
	MOV.W Rs,@(d:32,ERd)	>	7	80	0 erd	0	9 9	A		dsib	Q.			
	MOV.W Rs,@-ERd	>	9	۵	1 erd	ទ								
	MOV.W Rs,@aa:16	8	9	В	8	S.	al	abs						
	MOV.W Rs,@aa:32	>	9	В	٧	ទ		, a	abs					
	MOV.L #xx:32,ERd	_	7	A	0	0 erd		N.	IMM					
	MOV.L ERS,ERd	_	0	ш	1 ers	0 erd								
	MOV.L @ERS,ERd	_	0	1	0	0	6 9	0 ers 0 erd						
	MOV.L @(d:16,ERs),ERd	_	0	-	0	0	6 F	0 ers 0 erd	ō	dsib				
	MOV.L @(d:32,ERs),ERd	_	0	1	0	0	7 8	0 ers 0	9 9	2 0 erd		dis	dsip	
	MOV.L @ERs+,ERd	_	0	1	0	0	6 D	0 ers 0 erd						
	MOV.L @aa:16 ,ERd	_	0	-	0	0	6 B	0 0 erd	Ö	abs				
	MOV.L @aa:32 ,ERd	٦	0	1	0	0	6 B	2 0 erd		abs	S			
	MOV.L ERs,@ERd	_	0	-	0	0	6 9	1 erd 0 ers						
	MOV.L ERs, @(d:16,ERd)	_	0	-	0	0	6 F	1 erd 0 ers	ਰ	disp				
	MOV.L ERs,@(d:32,ERd)*1	_	0	-	0	0	7 8	0 erd 0	9 9	A 0 ers		di	disp	
	MOV.L ERs, @-ERd	_	0	-	0	0	Q 9	1 erd 0 ers						
	MOV.L ERs,@aa:16	_	0	-	0	0	6 B	8 0 ers	ซิ	abs				
	MOV.L ERs,@aa:32	7	0	1	0	0	6 B	A 0 ers		abs	S			
MOVFPE	MOVFPE MOVFPE @aa:16,Rd	В	Can	not be u	used in	the H8	Cannot be used in the H8S/2357 Series	S						
MOVTPE	MOVTPE MOVTPE Rs,@aa:16	В												
MULXS	MULXS.B Rs,Rd	В	0	-	ပ	0	5 0	rs rd						
	MULXS.W Rs, ERd	>	0	-	ပ	0	5 2	rs 0 erd						
MULXU	MULXU MULXU.B RS,Rd	В	2	0	গ্ৰ	5								
	MULXU.W Rs,ERd	>	2	2	S	0 erd								

-petrilo-									Instruction Format	n Format				
tion	Mnemonic	Size	1st k	1st byte	2nd byte	yte	3rd byte	4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
NEG	NEG.B Rd	В	-	7	8	rd								
	NEG.W Rd	Μ	-	7	6	Б								
	NEG.L ERd	٦	-	7	В	0 erd								
NOP	NOP	1	0	0	0	0								
NOT	NOT.B Rd	В	1	7	0	rd								
	NOT.W Rd	8	-	7	-	p								
	NOT.L ERd	٦	1	7	3	0 erd								
OR	OR.B #xx:8,Rd	В	၁	rd	IMM	5								
	OR.B Rs,Rd	В	-	4	S	ъ								
	OR.W #xx:16,Rd	M	7	6	4	p	M	IMM						
	OR.W Rs,Rd	M	9	4	S	p								
	OR.L #xx:32,ERd	٦	7	A	4	0 erd		MI	IMM					
	OR.L ERS,ERd	٦	0	1	ь	0	6 4	0 ers 0 erd						
ORC	ORC #xx:8,CCR	В	0	4	IMM	>								
	ORC #xx:8,EXR	В	0	1	4	1	0 4	IMM						
POP	POP.W Rn	M	9	D	7	L.								
	POP.L ERn	٦	0	1	0	0	6 D	7 0 ern						
PUSH	PUSH.W Rn	8	9	٥	Ŀ	٤								
	PUSH.L ERn	٦	0	1	0	0	6 D	F 0 ern						
ROTL	ROTL.B Rd	В	-	2	8	rd								
	ROTL.B #2, Rd	В	-	2	ပ	p								
	ROTL.W Rd	>	-	2	6	Б								
	ROTL.W #2, Rd	>	-	2	Δ	Б								
	ROTL.L ERd	_	-	2	<u></u> М	0 erd								
	ROTL.L #2, ERd	_	-	2	ш	0 erd								

Instruc-	Mnemonic	i							Instruction Format	n Format				
tion		0170	1st l	1st byte	2nd byte	byte	3rd byte	4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
ROTR	ROTR.B Rd	В	1	3	8	rd								
	ROTR.B #2, Rd	В	-	က	ပ	ā								
	ROTR.W Rd	≯	-	က	6	ā								
	ROTR.W #2, Rd	≯	-	က	۵	ā								
	ROTR.L ERd	_	-	က	а	0 erd								
	ROTR.L #2, ERd	_	-	3	ш	0 erd								
ROTXL	ROTXL.B Rd	В	-	2	0	Þ								
	ROTXL.B #2, Rd	М	-	2	4	ā								
	ROTXL.W Rd	>	-	2	-	ā								
	ROTXL.W #2, Rd	>	-	2	2	ā								
	ROTXL.L ERd	_	-	2	т	0 erd								
	ROTXL.L #2, ERd	_	-	2	7	0 erd								
ROTXR	ROTXR.B Rd	В	1	3	0	rd								
	ROTXR.B #2, Rd	В	-	3	4	Þ								
	ROTXR.W Rd	>	-	က	-	ā								
	ROTXR.W #2, Rd	×	1	3	2	rd								
	ROTXR.L ERd	_	-	3	3	0 erd								
	ROTXR.L #2, ERd	٦	1	3	7	0 erd								
RTE	RTE	Ι	2	9	7	0								
RTS	RTS	Ι	2	4	7	0								
SHAL	SHAL.B Rd	В	1	0	8	rd								
	SHAL.B #2, Rd	В	-	0	၁	p.								
	SHAL.W Rd	8	-	0	6	p.								
	SHAL.W #2, Rd	8	-	0	۵	p.								
	SHAL.L ERd	_	-	0	М	0 erd								
	SHAL.L #2, ERd	_	-	0	ш	0 erd								

o tri											Instruction Format	ion For	mat				
tion	Mnemonic	Size	1st	1st byte	2nd	2nd byte	3rd byte	و ا	4th byte		5th byte	eth	6th byte	7th byte	8th byte	9th byte	10th byte
SHAR	SHAR.B Rd	В	-	-	8	p											
	SHAR.B #2, Rd	В	-	-	ပ	Þ											
	SHAR.W Rd	8	-	1	6	p											
	SHAR.W #2, Rd	8	-	1	٥	p											
	SHAR.L ERd	_	-	1	В	0 erd											
	SHAR.L #2, ERd	_	1	1	Ь	0 erd											
SHLL	SHLL.B Rd	В	1	0	0	rd											
	SHLL.B #2, Rd	В	-	0	4	p											
	SHLL.W Rd	>	-	0	1	Þ											
	SHLL.W #2, Rd	8	-	0	2	p											
	SHLL.L ERd	٦	-	0	3	0 erd											
	SHLL.L #2, ERd	_	1	0	7	0 erd											
SHLR	SHLR.B Rd	В	1	1	0	rd											
	SHLR.B #2, Rd	В	-	1	4	p											
	SHLR.W Rd	8	-	1	1	p											
	SHLR.W #2, Rd	>	-	1	2	5											
	SHLR.L ERd	_	-	1	3	0 erd											
	SHLR.L #2, ERd	_	1	1	7	0 erd											
SLEEP	SLEEP	Ι	0	1	8	0											
STC	STC.B CCR,Rd	В	0	2	0	Þ											
	STC.B EXR,Rd	В	0	2	-	5											
	STC.W CCR,@ERd	>	0	1	4	0	9	9 1	erd	0							
	STC.W EXR,@ERd	>	0	1	4	-	9	9	erd	0							
	STC.W CCR,@(d:16,ERd)	>	0	1	4	0	9	Р 1	erd	0	-	dsip					
	STC.W EXR, @ (d:16, ERd)	>	0	1	4	-	9	Р 1	erd	0	-	disp					
	STC.W CCR,@(d:32,ERd)	8	0	1	4	0	7	8 0	erd	0	6 B	4	0		disp	ds	
	STC.W EXR, @ (d:32, ERd)	>	0	1	4	-	7	8	erd	0	6 B	∢	0		dsip	ds	
	STC.W CCR,@-ERd	8	0	1	4	0	9	D 1	erd	0							
	STC.W EXR,@-ERd	>	0	-	4	-	9	D 1	1 erd	0							

Instruc-	Mnemonic	ا ا] 							Instruction	Instruction Format				
tion		Size	1st k	st byte	2nd byte	byte	3rd byte		4th byte	5th byte	6th byte	7th byte	8th byte	9th byte	10th byte
STC	STC.W CCR,@aa:16	M	0	1	4	0	9 9	8 8	0	а	abs				
	STC.W EXR,@aa:16	8	0	1	4	1	9 9	8	0	a	abs				
	STC.W CCR,@aa:32	8	0	1	4	0	9 9	8 A	0		al	abs			
	STC.W EXR,@aa:32	>	0	1	4	1	9 9	8 A	0		al	abs			
STM	STM.L(ERn-ERn+1), @-SP	7	0	1	1	0	9 9) F	0 ern						
	STM.L (ERn-ERn+2), @-SP	_	0	-	2	0	О 9	Т .	0 ern						
	STM.L (ERn-ERn+3), @-SP	٦	0	-	က	0	9 9	Т.	0 ern						
STMAC	STMAC MACH,ERd	_	Canr	າot be ເ	used in	the H8	Cannot be used in the H8S/2357 Series	ries							
	STMAC MACL,ERd	_													
SUB	SUB.B Rs,Rd	а	-	∞	S.	Б									
	SUB.W #xx:16,Rd	≥	7	6	3	Б		MM							
	SUB.W Rs,Rd	≥	-	6	rs	ā									
	SUB.L #xx:32,ERd	_	7	4	3	0 erd			\	IMM					
	SUB.L ERS,ERd	Г	1	А	1 ers	0 erd									
SUBS	SUBS #1,ERd	_	-	В	0	0 erd									
	SUBS #2,ERd	_	-	В	8	0 erd									
	SUBS #4,ERd	_	-	В	6	0 erd									
SUBX	SUBX #xx:8,Rd	Ф	Ф	Б	IMM	Σ									
	SUBX Rs,Rd	В	1	Е	rs	rd									
TAS	TAS @ERd*2	В	0	1	В	0	7 B	0	erd C						
TRAPA	TRAPA #x:2	Τ	2	7	MMI:00	0									
XOR	XOR.B #xx:8,Rd	В	O	rd	ММІ	Ψ									
	XOR.B Rs,Rd	В	-	5	rs	Б									
	XOR.W #xx:16,Rd	8	7	6	2	Б		IMM							
	XOR.W Rs,Rd	>	9	2	ร	Б									
	XOR.L #xx:32,ERd	_	7	٧	2	0 erd			¥I	IMM					
	XOR.L ERS,ERd	_	0	1	ш	0	9		0 ers 0 erd						

Instruc-	Mnemonic						Instructio	Instruction Format				
tion		9716	1st byte	2nd byte	3rd byte 4th byte	4th byte	5th byte	6th byte 7th byte 8th byte 9th byte	7th byte	8th byte	9th byte	10th byte
XORC	XORC #xx:8,CCR	В	0 5	IMM								
	XORC #xx:8,EXR	В	0 1	4 1	0 5	IMM						

Notes: 1. Bit 7 of the 4th byte of the MOV.L ERs, @(d:32,ERd) instruction can be either 1 or 0.

2. Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction.

Legend

Immediate data (2, 3, 8, 16, or 32 bits) ΜM abs:

Absolute address (8, 16, 24, or 32 bits)

Displacement (8, 16, or 32 bits) disp:

Register field (4 bits specifying an 8-bit or 16-bit register. The symbols rs, rd, and rn correspond to operand symbols Rs, Rd,and Rn.) Register field (3 bits specifying an address register or 32-bit register. The symbols ers, erd, ern, and erm correspond to operand ers, erd, ern, erm: rs, rd, rn:

symbols ERs, ERd, ERn, and ERm.)

The register fields specify general registers as follows.

Address Regist 32-Bit Register	Address Register 32-Bit Register	16-Bit	16-Bit Register	8-Bit	8-Bit Register
Register Field	General Register	Register Field	General Register	Register Field	General Register
000	ERO	0000	RO	0000	ROH
100	ER1	0001	R1	0001	R1H
•	•	•	•	•	•
•	•	•	•	•	•
•	•	•	•	•	•
111	ER7	0111	R7	0111	R7H
		1000	E0	1000	ROL
		1001	E1	1001	R1L
		•	•	•	•
		•	•	•	•
		•	•	•	•
		1111	E7	1111	R7L

Operation Code Map A.3

Table A-3 shows the operation code map.

Table A-3 Operation Code Map (1)

2nd byte	BL
2nd	ВН
1st byte	AL
1st	АН
Instruction code	

l byte	Instruction when most significant bit of BH is 0.	Instruction when most significant bit of BH is 1
	2nd byte	BL
		AL

L	Table A.3(2)	Table A.3(2)			BLE											
ш	ADDX	SUBX			BGT	JSR		Table A.3(3)								
٥	2	CMP			BLT		MOV	Tabl								
ပ	MOV	CN			BGE	BSR										
В	Table A.3(2)	Table A.3(2)			BMI			EEPMOV								
4	Table A.3(2)	Table A.3(2)			BPL	JMP	Table A.3(2)									
6	ADD	SUB			BVS		2	Table A.3(2)								
8	ΑΓ	รเ	ú	zi Zi	BVC	Table A.3(2)	MOV	MOV	٥	ADDX	CMP	×	OR	XOR	AND	۸(
7	ГРС	Table A.3(2)		MOV SE	BEQ	TRAPA	BST // BIST		ADD	AD	อี	SUBX	0	X	A	MOV
9	ANDC	AND			BNE	RTE		BAND BIAND								
2	XORC	XOR			BCS	BSR	XOR	SXOR BIXOF								
4	ORC	OR			ВСС	RTS	OR	BOR BIOR								
3	LDC LDMAC	Table A.3(2)			BLS	DIVXU		<u>0</u>								
2	STC **	Table A.3(2)			핆	MULXU	0	BCLR								
_	1	Table A.3(2)			BRN	DIVXU	Š									
0	NOP	Table A.3(2)			BRA	MULXU	H C	- BOE								
AH AH	0	7	2	3	4	2	9	7	8	6	4	В	C	D	Е	F

Note: * Cannot be used in the H8S/2357 Series.

Table A-3 Operation Code Map (2)

2nd byte	В
2nd	ВН
1st byte	AL
1st	АН
Instruction code	

ш	Table A.3(3)		NC NC		SHAL	SHAR	ROTL	ROTR	EXTS		DEC		BLE			
ш	TAS												BGT			
٥	Table A.3(3)		NC						EXTS		DEC		BLT			
O	Table A.3(3)	Q		MOV	SHAL	SHAR	ROTL	ROTR		<u></u>		ΙΡ	BGE	MOVTPE*		
В		ADD		MO					NEG	SUB		CMP	BMI			
∢	CLRMAC*												BPL	MOV		
6			ADDS		AL	AR	7	TR	Ö		BS		BVS			
80	SLEEP		AD		SHAL	SHAR	ROTL	ROTR	NEG		SUBS		BVC	MOV		
7			NC		SHLL	SHLR	ROTXL	ROTXR	EXTU		DEC		BEQ			
9	MAC*												BNE		AND	AND
2			NC						EXTU		DEC		BCS		XOR	XOR
4	LDC				SHLL	SHLR	ROTXL	ROTXR					BCC	MOVFPE*	OR	NO.
က	STM								NOT				BLS	Table A.3(4)	SUB	SUB
2													BHI	MOV	CMP	CMP
-	LDM				SHLL	SHLR	ROTXL	ROTXR)T				BRN	Table A.3(4)	ADD	ADD
0	MOV	INC	ADDS	DAA	SH	RS	RO.	ROī	NOT	DEC	SUBS	DAS	BRA	MOV	MOV	MOV
AH AI	10	0A	0B	0F	10	11	12	13	17	1A	18	1F	28	6A	79	7A

Note: * Cannot be used in the H8S/2357 Series.

Table A-3 Operation Code Map (3)

byte	Ы
4th I	ВН
3rd byte	CL
3rd	공
2nd byte	BL
2nd	ВН
1st byte	AL
1st	АН
Instruction code	

Instruction when most significant bit of DH is 0. Instruction when most significant bit of DH is 1.

н											
Е											
D											
С											
В											
Α											
6											
8											
7					BLD BILD	BST BIST			BLD BLD	BST	
9			AND		BAND				BAND BIAND		
5			XOR		XOR BIXC				XOR BIXO		
4			OR		BTST BOR BIOR				BOR BIOR		
3		DIVXS		BTST	BTST			BTST	BTST		
2	MULXS					BCLR	BCLR			BCLR	BCLR
1		DIVXS				BNOT	BNOT			BNOT	BNOT
0	SXTNW					BSET	BSET			BSET	BSET
AH AL BH BL CH	01C05	01D05	01F06	7Cr06 *1	7Cr07 *1	7Dr06 *1	7Dr07 *1	7Eaa6 *2	7Eaa7 *2	7Faa6 *2	7Faa7 *2

Notes: 1. r is the register specification field.

2. aa is the absolute address specification.

Table A-3 Operation Code Map (4)

6th byte	FL
6th	FH
5th byte	EL
5th	표
th byte	DL
4th	Ы
3rd byte	CL
3rd	СН
and byte	BL
2nd	ВН
st byte	AL
1st	AH
Instruction code	

												InstructInstruct	ion when ion when	nost sign nost sign	ficant bit of ficant bit	 Instruction when most significant bit of FH is 0. Instruction when most significant bit of FH is 1.
AHALBHBLCHCLDHDLEH	0	-	2	3	4	5	9	7	8	6	4	В	С	D	Е	ш
6A10aaaa6*				H C												
6A10aaaa7*				0	BOR BIOR	BXOR I	BAND	BISI BOR BXOR BAND BLD BIOR BIXOR BIAND BILD								
6A18aaaa6*	F100	- CAG	2					BST BIST								
6A18aaaa7*	BOE	ONIG	DCLN													

3th byte	Ⅎ
8th	壬
7th byte	GL
7th	В Н
ith byte	긥
6th	표
5th byte	П
9th	НЗ
th byte	DL
4th I	H
ard byte	CL
3rd	НЭ
nd byte	BL
2nd	ВН
st byte	AL
1st	АН
Instruction code	

- Instruction when most significant bit of HH is 0. - Instruction when most significant bit of HH is 1.

ь				
Е				
D				
၁				
В				
A				
6				
8				
7		BLD BILD	BST BIST	
9		BAND BIAND		
5		BXOR BIXOR		
4		BOR BXOR BAND BLD BIOR BIXOR BIAND		
3	FOFO	0		
2			-	DCLR
1			TONG.	
0			1	DOU
AHALBHBL FHFLGH	6A30aaaaaaaa6*	6A30aaaaaaa7*	6A38aaaaaaa6*	6A38aaaaaaa7*

Note: * aa is the absolute address specification.

A.4 Number of States Required for Instruction Execution

The tables in this section can be used to calculate the number of states required for instruction execution by the CPU. Table A-5 indicates the number of instruction fetch, data read/write, and other cycles occurring in each instruction. Table A-4 indicates the number of states required for each cycle. The number of states required for execution of an instruction can be calculated from these two tables as follows:

Execution states =
$$I \times S_I + J \times S_J + K \times S_K + L \times S_L + M \times S_M + N \times S_N$$

Examples: Advanced mode, program code and stack located in external memory, on-chip supporting modules accessed in two states with 8-bit bus width, external devices accessed in three states with one wait state and 16-bit bus width.

1. BSET #0. @FFFFC7:8

From table A-5:

$$I = L = 2$$
, $J = K = M = N = 0$

From table A-4:

$$S_1 = 4$$
, $S_1 = 2$

Number of states required for execution = $2 \times 4 + 2 \times 2 = 12$

2. JSR @@30

From table A-5:

$$I = J = K = 2$$
, $L = M = N = 0$

From table A-4:

$$S_{I} = S_{I} = S_{K} = 4$$

Number of states required for execution = $2 \times 4 + 2 \times 4 + 2 \times 4 = 24$

Table A-4 Number of States per Cycle

A	O	-124	:	
Access	Con	ait	IOI	าร

			On-Chip Supporting			Externa	al Device	
			Module	3	8-Bi	t Bus	16-B	it Bus
Cycle		On-Chip Memory		16-Bit Bus		3-State Access		
Instruction fetch	Sı	1	4	2	4	6 + 2m	2	3 + m
Branch address read	S _J	_						
Stack operation	S_{κ}	_						
Byte data access	S _L	_	2		2	3 + m		
Word data access	$S_{\scriptscriptstyle M}$	_	4		4	6 + 2m	-	
Internal operation	S_N	1	1	1	1	1	1	1

Legend

m: Number of wait states inserted into external device access

Table A-5 Number of Cycles in Instruction Execution

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
ADD	ADD.B #xx:8,Rd	1					
	ADD.B Rs,Rd	1					
	ADD.W #xx:16,Rd	2					
	ADD.W Rs,Rd	1					
	ADD.L #xx:32,ERd	3					
	ADD.L ERs,ERd	1					
ADDS	ADDS #1/2/4,ERd	1					
ADDX	ADDX #xx:8,Rd	1					
	ADDX Rs,Rd	1					
AND	AND.B #xx:8,Rd	1					
	AND.B Rs,Rd	1					
	AND.W #xx:16,Rd	2					
	AND.W Rs,Rd	1					
	AND.L #xx:32,ERd	3					
	AND.L ERs,ERd	2					
ANDC	ANDC #xx:8,CCR	1					
	ANDC #xx:8,EXR	2					
BAND	BAND #xx:3,Rd	1					
	BAND #xx:3,@ERd	2			1		
	BAND #xx:3,@aa:8	2			1		
	BAND #xx:3,@aa:16	3			1		
	BAND #xx:3,@aa:32	4			1		
Всс	BRA d:8 (BT d:8)	2					
	BRN d:8 (BF d:8)	2					
	BHI d:8	2					
	BLS d:8	2					
	BCC d:8 (BHS d:8)	2					
	BCS d:8 (BLO d:8)	2					
	BNE d:8	2					
	BEQ d:8	2					
	BVC d:8	2					
	BVS d:8	2					
	BPL d:8	2					

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
Всс	BMI d:8	2					
	BGE d:8	2					
	BLT d:8	2					
	BGT d:8	2					
	BLE d:8	2					
	BRA d:16 (BT d:16)	2					1
	BRN d:16 (BF d:16)	2					1
	BHI d:16	2					1
	BLS d:16	2					1
	BCC d:16 (BHS d:16)	2					1
	BCS d:16 (BLO d:16)	2					1
	BNE d:16	2					1
	BEQ d:16	2					1
	BVC d:16	2					1
	BVS d:16	2					1
	BPL d:16	2					1
	BMI d:16	2					1
	BGE d:16	2					1
	BLT d:16	2					1
	BGT d:16	2					1
	BLE d:16	2					1
BCLR	BCLR #xx:3,Rd	1					
	BCLR #xx:3,@ERd	2			2		
	BCLR #xx:3,@aa:8	2			2		
	BCLR #xx:3,@aa:16	3			2		
	BCLR #xx:3,@aa:32	4			2		
	BCLR Rn,Rd	1					
	BCLR Rn,@ERd	2			2		
	BCLR Rn,@aa:8	2			2		
	BCLR Rn,@aa:16	3			2		
	BCLR Rn,@aa:32	4			2		

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
BIAND	BIAND #xx:3,Rd	1					
	BIAND #xx:3,@ERd	2			1		
	BIAND #xx:3,@aa:8	2			1		
	BIAND #xx:3,@aa:16	3			1		
	BIAND #xx:3,@aa:32	4			1		
BILD	BILD #xx:3,Rd	1					
	BILD #xx:3,@ERd	2			1		
	BILD #xx:3,@aa:8	2			1		
	BILD #xx:3,@aa:16	3			1		
	BILD #xx:3,@aa:32	4			1		
BIOR	BIOR #xx:8,Rd	1					
	BIOR #xx:8,@ERd	2			1		
	BIOR #xx:8,@aa:8	2			1		
	BIOR #xx:8,@aa:16	3			1		
	BIOR #xx:8,@aa:32	4			1		
BIST	BIST #xx:3,Rd	1					
	BIST #xx:3,@ERd	2			2		
	BIST #xx:3,@aa:8	2			2		
	BIST #xx:3,@aa:16	3			2		
	BIST #xx:3,@aa:32	4			2		
BIXOR	BIXOR #xx:3,Rd	1					
	BIXOR #xx:3,@ERd	2			1		
	BIXOR #xx:3,@aa:8	2			1		
	BIXOR #xx:3,@aa:16	3			1		
	BIXOR #xx:3,@aa:32	4			1		
BLD	BLD #xx:3,Rd	1					
	BLD #xx:3,@ERd	2			1		
	BLD #xx:3,@aa:8	2			1		
	BLD #xx:3,@aa:16	3			1		
	BLD #xx:3,@aa:32	4			1		

			Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic		Ī	J	K	L	М	N
BNOT	BNOT #xx:3	,Rd	1					
	BNOT #xx:3	,@ERd	2			2		
	BNOT #xx:3	,@aa:8	2			2		
	BNOT #xx:3	,@aa:16	3			2		
	BNOT #xx:3	,@aa:32	4			2		
	BNOT Rn,Rd	d	1					
	BNOT Rn,@	ERd	2			2		
	BNOT Rn,@	aa:8	2			2		
	BNOT Rn,@	aa:16	3			2		
	BNOT Rn,@	aa:32	4			2		
BOR	BOR #xx:3,F	Rd	1					
	BOR #xx:3,@	@ERd	2			1		
	BOR #xx:3,@	②aa:8	2			1		
	BOR #xx:3,@	2aa:16	3			1		
	BOR #xx:3,@	@aa:32	4			1		
BSET	BSET #xx:3,	Rd	1					
	BSET #xx:3,	@ERd	2			2		
	BSET #xx:3,	@aa:8	2			2		
	BSET #xx:3,	@aa:16	3			2		
	BSET #xx:3,	@aa:32	4			2		
	BSET Rn,Rc	I	1					
	BSET Rn,@	ERd	2			2		
	BSET Rn,@	aa:8	2			2		
	BSET Rn,@	aa:16	3			2		
	BSET Rn,@	aa:32	4			2		
BSR	BSR d:8	Advanced	2		2			
	BSR d:16	Advanced	2		2			1
BST	BST #xx:3,R	d	1					
	BST #xx:3,@	ERd	2			2		
	BST #xx:3,@aa:8		2			2		
	BST #xx:3,@	aa:16	3			2		
	BST #xx:3,@	aa:32	4			2		

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	Ī	J	K	L	М	N
BTST	BTST #xx:3,Rd	1					
	BTST #xx:3,@ERd	2			1		
	BTST #xx:3,@aa:8	2			1		
	BTST #xx:3,@aa:16	3			1		
	BTST #xx:3,@aa:32	4			1		
	BTST Rn,Rd	1					
	BTST Rn,@ERd	2			1		
	BTST Rn,@aa:8	2			1		
	BTST Rn,@aa:16	3			1		
	BTST Rn,@aa:32	4			1		
BXOR	BXOR #xx:3,Rd	1					
	BXOR #xx:3,@ERd	2			1		
	BXOR #xx:3,@aa:8	2			1		
	BXOR #xx:3,@aa:16	3			1		
	BXOR #xx:3,@aa:32	4			1		
CLRMAC	CLRMAC	Cannot be us	sed in the F	18S/2357 Sei	ries		
CMP	CMP.B #xx:8,Rd	1					
	CMP.B Rs,Rd	1					
	CMP.W #xx:16,Rd	2					
	CMP.W Rs,Rd	1					
	CMP.L #xx:32,ERd	3					
	CMP.L ERs,ERd	1					
DAA	DAA Rd	1					
DAS	DAS Rd	1					
DEC	DEC.B Rd	1					
	DEC.W #1/2,Rd	1					
	DEC.L #1/2,ERd	1					
DIVXS	DIVXS.B Rs,Rd	2					11
	DIVXS.W Rs,ERd	2					19
DIVXU	DIVXU.B Rs,Rd	1					11
	DIVXU.W Rs,ERd	1					19

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	Ī	J	K	L	М	N
EEPMOV	EEPMOV.B	2			2n+2*2		
	EEPMOV.W	2			2n+2*2		
EXTS	EXTS.W Rd	1					
	EXTS.L ERd	1					
EXTU	EXTU.W Rd	1					
	EXTU.L ERd	1					
INC	INC.B Rd	1					
	INC.W #1/2,Rd	1					
	INC.L #1/2,ERd	1					
JMP	JMP @ERn	2					
	JMP @aa:24	2					1
	JMP @@aa:8 Advanced	2	2				1
JSR	JSR @ERn Advanced	2		2			
	JSR @aa:24 Advanced	2		2			1
	JSR @@aa:8 Advanced	2	2	2			
LDC	LDC #xx:8,CCR	1					
	LDC #xx:8,EXR	2					
	LDC Rs,CCR	1					
	LDC Rs,EXR	1					
	LDC @ERs,CCR	2				1	
	LDC @ERs,EXR	2				1	
	LDC @(d:16,ERs),CCR	3				1	
	LDC @(d:16,ERs),EXR	3				1	
	LDC @(d:32,ERs),CCR	5				1	
	LDC @(d:32,ERs),EXR	5				1	
	LDC @ERs+,CCR	2				1	1
	LDC @ERs+,EXR	2				1	1
	LDC @aa:16,CCR	3				1	
	LDC @aa:16,EXR	3				1	
	LDC @aa:32,CCR	4				1	
	LDC @aa:32,EXR	4				1	

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
LDM	LDM.L @SP+, (ERn-ERn+1)	2		4			1
	LDM.L @SP+, (ERn-ERn+2)	2		6			1
	LDM.L @SP+, (ERn-ERn+3)	2		8			1
LDMAC	LDMAC ERs,MACH	Cannot be u	sed in the F	18S/2357 Ser	ies		
	LDMAC ERs,MACL						
MAC	MAC @ERn+,@ERm+	Cannot be u	sed in the F	18S/2357 Ser	ies		
MOV	MOV.B #xx:8,Rd	1					
	MOV.B Rs,Rd	1					
	MOV.B @ERs,Rd	1			1		
	MOV.B @(d:16,ERs),Rd	2			1		
	MOV.B @(d:32,ERs),Rd	4			1		
	MOV.B @ERs+,Rd	1			1		1
	MOV.B @aa:8,Rd	1			1		
	MOV.B @aa:16,Rd	2			1		
	MOV.B @aa:32,Rd	3			1		
	MOV.B Rs,@ERd	1			1		
	MOV.B Rs,@(d:16,ERd)	2			1		
	MOV.B Rs,@(d:32,ERd)	4			1		
	MOV.B Rs,@-ERd	1			1		1
	MOV.B Rs,@aa:8	1			1		
	MOV.B Rs,@aa:16	2			1		
	MOV.B Rs,@aa:32	3			1		
	MOV.W #xx:16,Rd	2					
	MOV.W Rs,Rd	1					
	MOV.W @ERs,Rd	1				1	
	MOV.W @(d:16,ERs),Rd	2				1	
	MOV.W @(d:32,ERs),Rd	4				1	
	MOV.W @ERs+,Rd	1				1	1
	MOV.W @aa:16,Rd	2				1	
	MOV.W @aa:32,Rd	3				1	
	MOV.W Rs,@ERd	1				1	

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
MOV	MOV.W Rs,@(d:16,ERd)	2				1	
	MOV.W Rs,@(d:32,ERd)	4				1	
	MOV.W Rs,@-ERd	1				1	1
	MOV.W Rs,@aa:16	2				1	
	MOV.W Rs,@aa:32	3				1	
	MOV.L #xx:32,ERd	3					
	MOV.L ERs,ERd	1					
	MOV.L @ERs,ERd	2				2	
	MOV.L @(d:16,ERs),ERd	3				2	
	MOV.L @(d:32,ERs),ERd	5				2	
	MOV.L @ERs+,ERd	2				2	1
	MOV.L @aa:16,ERd	3				2	
	MOV.L @aa:32,ERd	4				2	
	MOV.L ERs,@ERd	2				2	
	MOV.L ERs,@(d:16,ERd)	3				2	
	MOV.L ERs,@(d:32,ERd)	5				2	
	MOV.L ERs,@-ERd	2				2	1
	MOV.L ERs,@aa:16	3				2	
	MOV.L ERs,@aa:32	4				2	
MOVFPE	MOVFPE @:aa:16,Rd	Can not be u	used in the l	H8S/2357 Se	eries		
MOVTPE	MOVTPE Rs,@:aa:16						
MULXS	MULXS.B Rs,Rd	2					11
	MULXS.W Rs,ERd	2					19
MULXU	MULXU.B Rs,Rd	1					11
	MULXU.W Rs,ERd	1					19
NEG	NEG.B Rd	1					
	NEG.W Rd	1					
	NEG.L ERd	1					
NOP	NOP	1					
NOT	NOT.B Rd	1					
	NOT.W Rd	1					
	NOT.L ERd	1					

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
OR	OR.B #xx:8,Rd	1					
	OR.B Rs,Rd	1					
	OR.W #xx:16,Rd	2					
	OR.W Rs,Rd	1					
	OR.L #xx:32,ERd	3					
	OR.L ERs,ERd	2					
ORC	ORC #xx:8,CCR	1					
	ORC #xx:8,EXR	2					
POP	POP.W Rn	1				1	1
	POP.L ERn	2				2	1
PUSH	PUSH.W Rn	1				1	1
	PUSH.L ERn	2				2	1
ROTL	ROTL.B Rd	1					
	ROTL.B #2,Rd	1					
	ROTL.W Rd	1					
	ROTL.W #2,Rd	1					
	ROTL.L ERd	1					
	ROTL.L #2,ERd	1					
ROTR	ROTR.B Rd	1					
	ROTR.B #2,Rd	1					
	ROTR.W Rd	1					
	ROTR.W #2,Rd	1					
	ROTR.L ERd	1					
	ROTR.L #2,ERd	1					
ROTXL	ROTXL.B Rd	1					
	ROTXL.B #2,Rd	1					
	ROTXL.W Rd	1					
	ROTXL.W #2,Rd	1					
	ROTXL.L ERd	1					
	ROTXL.L #2,ERd	1					

			Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic		Ī	J	К	L	М	N
ROTXR	ROTXR.B F	₹d	1					
	ROTXR.B#	#2,Rd	1					
	ROTXR.W	Rd	1					
	ROTXR.W	#2,Rd	1					
	ROTXR.L E	Rd	1					
	ROTXR.L#	£2,ERd	1					
RTE	RTE		2		2/3*1			1
RTS	RTS	Advanced	2		2			1
SHAL	SHAL.B Rd		1					
	SHAL.B #2	,Rd	1					
	SHAL.W R	d	1					
	SHAL.W #2	2,Rd	1					
	SHAL.L ER	d	1					
	SHAL.L #2,	,ERd	1					
SHAR	SHAR.B Ro	t	1					
	SHAR.B #2	.,Rd	1					
	SHAR.W R	d	1					
	SHAR.W #2	2,Rd	1					
	SHAR.L EF	Rd	1					
	SHAR.L #2	,ERd	1					
SHLL	SHLL.B Rd		1					
	SHLL.B #2,	,Rd	1					
	SHLL.W Ro	d	1					
	SHLL.W #2	,Rd	1					
	SHLL.L ER	d	1					
	SHLL.L #2,	ERd	1					
SHLR	SHLR.B Rd	l	1					
	SHLR.B #2	,Rd	1					
	SHLR.W R	d	1					
	SHLR.W #2	2,Rd	1					
	SHLR.L ER	td.	1					
	SHLR.L #2	,ERd	1					
SLEEP	SLEEP		1					1

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
STC	STC.B CCR,Rd	1					
	STC.B EXR,Rd	1					
	STC.W CCR,@ERd	2				1	
	STC.W EXR,@ERd	2				1	
	STC.W CCR,@(d:16,ERd)	3				1	
	STC.W EXR,@(d:16,ERd)	3				1	
	STC.W CCR,@(d:32,ERd)	5				1	
	STC.W EXR,@(d:32,ERd)	5				1	
	STC.W CCR,@-ERd	2				1	1
	STC.W EXR,@-ERd	2				1	1
	STC.W CCR,@aa:16	3				1	
	STC.W EXR,@aa:16	3				1	
	STC.W CCR,@aa:32	4				1	
	STC.W EXR,@aa:32	4				1	
	STM.L (ERn-ERn+1), @-SP	2		4			1
	STM.L (ERn-ERn+2), @-SP	2		6			1
	STM.L (ERn-ERn+3), @-SP	2		8			1
STMAC	STMAC MACH,ERd	Cannot be us	sed in the F	18S/2357 Ser	ies		
	STMAC MACL,ERd						
SUB	SUB.B Rs,Rd	1					
	SUB.W #xx:16,Rd	2					
	SUB.W Rs,Rd	1					
	SUB.L #xx:32,ERd	3					
	SUB.L ERs,ERd	1					
SUBS	SUBS #1/2/4,ERd	1					
SUBX	SUBX #xx:8,Rd	1					
	SUBX Rs,Rd	1					
TAS	TAS @ERd*3	2			2		
TRAPA	TRAPA #x:2 Advanced	2	2	2/3*1			2

		Instruction Fetch	Branch Address Read	Stack Operation	Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	K	L	М	N
XOR	XOR.B #xx:8,Rd	1					
	XOR.B Rs,Rd	1					
	XOR.W #xx:16,Rd	2					
	XOR.W Rs,Rd	1					
	XOR.L #xx:32,ERd	3					
	XOR.L ERs,ERd	2					
XORC	XORC #xx:8,CCR	1					
	XORC #xx:8,EXR	2					

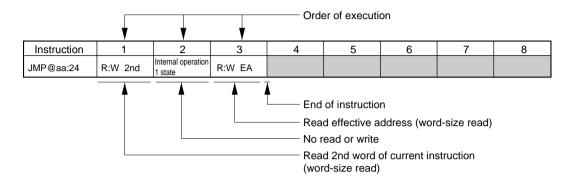
Notes: 1. 2 when EXR is invalid, 3 when EXR is valid.

- 2. When n bytes of data are transferred.
- 3. Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction.

A.5 Bus States During Instruction Execution

Table A-6 indicates the types of cycles that occur during instruction execution by the CPU. See table A-4 for the number of states per cycle.

How to Read the Table:



Legend

•	
R:B	Byte-size read
R:W	Word-size read
W:B	Byte-size write
W:W	Word-size write
:M	Transfer of the bus is not performed immediately after this cycle
2nd	Address of 2nd word (3rd and 4th bytes)
3rd	Address of 3rd word (5th and 6th bytes)
4th	Address of 4th word (7th and 8th bytes)
5th	Address of 5th word (9th and 10th bytes)
NEXT	Address of next instruction
EA	Effective address
VEC	Vector address

Figure A-1 shows timing waveforms for the address bus and the \overline{RD} , \overline{HWR} , and \overline{LWR} signals during execution of the above instruction with an 8-bit bus, using three-state access with no wait states.

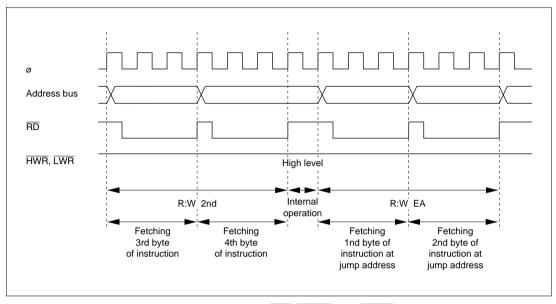


Figure A-1 Address Bus, RD, HWR, and LWR Timing (8-Bit Bus, Three-State Access, No Wait States)

Table A-6 Instruction Execution Cycles

doitor ratad	-	,	٣	<	Ľ	u	7	α	σ
ADD.B #xx:8.Rd	R:W NEXT					,		,	
ADD.B Rs,Rd	R:W NEXT								
ADD.W #xx:16,Rd	R:W 2nd	R:W NEXT							
ADD.W Rs,Rd	R:W NEXT								
ADD.L #xx:32,ERd	R:W 2nd	R:W 3rd	R:W NEXT						
ADD.L ERs,ERd	R:W NEXT								
ADDS #1/2/4,ERd	R:W NEXT								
ADDX #xx:8,Rd	R:W NEXT								
ADDX Rs,Rd	R:W NEXT								
AND.B #xx:8,Rd	R:W NEXT								
AND.B Rs,Rd	R:W NEXT								
AND.W #xx:16,Rd	R:W 2nd	R:W NEXT							
AND.W Rs,Rd	R:W NEXT								
AND.L #xx:32,ERd	R:W 2nd	R:W 3rd	R:W NEXT						
AND.L ERS,ERd	R:W 2nd	R:W NEXT							
ANDC #xx:8,CCR	R:W NEXT								
ANDC #xx:8,EXR	R:W 2nd	R:W NEXT							
BAND #xx:3,Rd	R:W NEXT								
BAND #xx:3, @ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BAND #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BAND #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BAND #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BRA d:8 (BT d:8)	R:W NEXT	R:W EA							
BRN d:8 (BF d:8)	R:W NEXT	R:W EA							
BHI d:8	R:W NEXT	R:W EA							
BLS d:8	R:W NEXT	R:W EA							
BCC d:8 (BHS d:8)	R:W NEXT	R:W EA							
BCS d:8 (BLO d:8)	R:W NEXT	R:W EA							
BNE d:8	R:W NEXT	R:W EA							
BEQ d:8	R:W NEXT	R:W EA							
BVC d:8	R:W NEXT	R:W EA							
BVS d:8	R:W NEXT	R:W EA							
BPL d:8	R:W NEXT	R:W EA							
BMI d:8	R:W NEXT	R:W EA							
BGE d:8	R:W NEXT	R:W EA							
BLT d:8	R:W NEXT	R:W EA							
BGT d:8	R:W NEXT	R:W EA							

Instruction	-	2	3	4	2	9	7	8	6
BLE d:8	R:W NEXT	R:W EA							
BRA d:16 (BT d:16)	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BRN d:16 (BF d:16)	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BHI d:16	R:W 2nd	Internal operation, 1 state	R:W EA						
BLS d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BCC d:16 (BHS d:16)	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BCS d:16 (BLO d:16)	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BNE d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BEQ d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BVC d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BVS d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BPL d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BMI d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BGE d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BLT d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BGT d:16	R:W 2nd	Internal operation, 1 state	R:W EA						
BLE d:16	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
BCLR #xx:3,Rd	R:W NEXT								
BCLR #xx:3,@ERd	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BCLR #xx:3, @aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA						
BCLR #xx:3,@aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				

Instruction	-	2	3	4	2	9	7	8	6
BCLR #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BCLR Rn,Rd	R:W NEXT								
BCLR Rn, @ERd	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BCLR Rn, @aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BCLR Rn, @aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				
BCLR Rn, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BIAND #xx:3,Rd	R:W NEXT								
BIAND #xx:3, @ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BIAND #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BIAND #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BIAND #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BILD #xx:3,Rd	R:W NEXT								
BILD #xx:3,@ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BILD #xx:3,@aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BILD #xx:3,@aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BILD #xx:3,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BIOR #xx:3,Rd	R:W NEXT								
BIOR #xx:3, @ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BIOR #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BIOR #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BIOR #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BIST #xx:3,Rd	R:W NEXT								
BIST #xx:3,@ERd	R:W 2nd	R:B:M EA	R:W:M NEXT	W:B EA					
BIST #xx:3,@aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT	W:B EA					
BIST #xx:3,@aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				
BIST #xx:3,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BIXOR #xx:3,Rd	R:W NEXT								
BIXOR #xx:3, @ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BIXOR #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BIXOR #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BIXOR #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BLD #xx:3,Rd	R:W NEXT								
BLD #xx:3, @ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BLD #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BLD #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BLD #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BNOT #xx:3,Rd	R:W NEXT								

Instruction	-	2	е	4	2	9	7	8	6
BNOT #xx:3, @ERd	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BNOT #xx:3, @aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BNOT #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA				
BNOT #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT W:B EA	W:B EA			
BNOT Rn,Rd	R:W NEXT								
BNOT Rn, @ERd	R:W 2nd	R:B:M EA	R:W:M NEXT	W:B EA					
BNOT Rn, @aa:8	R:W 2nd	R:B:M EA	X	W:B EA					
BNOT Rn, @aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				
BNOT Rn, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BOR #xx:3,Rd	R:W NEXT								
BOR #xx:3,@ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BOR #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BOR #xx:3,@aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BOR #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BSET #xx:3,Rd	R:W NEXT								
BSET #xx:3, @ERd	R:W 2nd	R:B:M EA	R:W:M NEXT	W:B EA					
BSET #xx:3, @aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BSET #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				
BSET #xx:3,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BSET Rn,Rd	R:W NEXT								
BSET Rn, @ERd	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BSET Rn, @aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BSET Rn, @aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				
BSET Rn, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BSR d:8 Advanced	R:W NEXT	R:W EA	W:W:M stack (H)	W:W stack (L)					
BSR d:16 Advanced	R:W 2nd	Internal operation, R:W EA	R:W EA	W:W:M stack (H) W:W stack (L)	W:W stack (L)				
		1 state							
BST #xx:3,Rd	R:W NEXT								
BST #xx:3,@ERd	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BST #xx:3,@aa:8	R:W 2nd	R:B:M EA	R:W:M NEXT W:B EA	W:B EA					
BST #xx:3,@aa:16	R:W 2nd	R:W 3rd	R:B:M EA	R:W:M NEXT	W:B EA				
BST #xx:3,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B:M EA	R:W:M NEXT	W:B EA			
BTST #xx:3,Rd	R:W NEXT								
BTST #xx:3,@ERd	R:W 2nd	R:B EA	R:W:M NEXT						

Instruction	-	2	3	4	5	9	7	8	6
BTST #xx:3, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BTST #xx:3, @aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BTST #xx:3, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BTST Rn,Rd	R:W NEXT								
BTST Rn, @ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BTST Rn, @aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BTST Rn,@aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BTST Rn,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
BXOR #xx:3,Rd	R:W NEXT								
BXOR #xx:3,@ERd	R:W 2nd	R:B EA	R:W:M NEXT						
BXOR #xx:3,@aa:8	R:W 2nd	R:B EA	R:W:M NEXT						
BXOR #xx:3,@aa:16	R:W 2nd	R:W 3rd	R:B EA	R:W:M NEXT					
BXOR #xx:3,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:B EA	R:W:M NEXT				
CLRMAC	Cannot be use	Cannot be used in the H8S/2357 Series	357 Series						
CMP.B #xx:8,Rd	R:W NEXT								
CMP.B Rs,Rd	R:W NEXT								
CMP.W #xx:16,Rd	R:W 2nd	R:W NEXT							
CMP.W Rs,Rd	R:W NEXT								
CMP.L #xx:32,ERd	R:W 2nd	R:W 3rd	R:W NEXT						
CMP.L ERs, ERd	R:W NEXT								
DAA Rd	R:W NEXT								
DAS Rd	R:W NEXT								
DEC.B Rd	R:W NEXT								
DEC.W #1/2,Rd	R:W NEXT								
DEC.L #1/2,ERd	R:W NEXT								
DIVXS.B Rs,Rd	R:W 2nd	R:W NEXT	Internal operation, 11 states	ion, 11 states					
DIVXS.W Rs, ERd	R:W 2nd	R:W NEXT	Internal operation, 19 states	ion, 19 states					
DIVXU.B Rs,Rd	R:W NEXT	Internal opera	Internal operation, 11 states						
DIVXU.W Rs, ERd	R:W NEXT	Internal opera	Internal operation, 19 states						
EEPMOV.B	R:W 2nd	R:B EAs*1	R:B EAd*1	R:B EAs*2	W:B EAd*2	R:W NEXT			
EEPMOV.W	R:W 2nd	R:B EAs*1	R:B EAd*1	R:B EAs*2	W:B EAd*2	R:W NEXT			
EXTS.W Rd	R:W NEXT			\leftarrow Repeated	Repeated n times $^{*2} \rightarrow$				
EXTS.L ERd	R:W NEXT								
EXTU.W Rd	R:W NEXT								
EXTU.L ERd	R:W NEXT								
INC.B Rd	R:W NEXT								

Instruction		1	2	3	4	5	9	7	8	6
INC.W #1/2,Rd		R:W NEXT								
INC.L #1/2,ERd		R:W NEXT								
JMP @ERn		R:W NEXT	R:W EA							
JMP @aa:24		R:W 2nd	Internal operation, R:W EA 1 state	R:W EA						
JMP @@aa:8 N	Normal	R:W NEXT	R:W aa:8	Internal operation, R:W EA 1 state	R:W EA					
¥	Advanced	R:W NEXT	R:W:M aa:8	R:W aa:8	Internal operation, R:W EA 1 state	R:W EA				
JSR @ERn N	Normal	R:W NEXT	R:W EA	W:W stack						
Ac	Advanced	R:W NEXT	R:W EA	W:W:M stack (H) W:W stack (L)	W:W stack (L)					
JSR @aa:24 N	Normal	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA	W:W stack					
¥	Advanced	R:W 2nd	Internal operation, R:W EA 1 state	R:W EA	W:W:M stack (H) W:W stack (L)	W:W stack (L)				
JSR @@aa:8 N	Normal	R:W NEXT	R:W aa:8	W:W stack	R:W EA					
Ĭ	Advanced	R:W NEXT	R:W:M aa:8	R:W aa:8	W:W:M stack (H) W:W stack (L)	W:W stack (L)	R:W EA			
LDC #xx:8,CCR		R:W NEXT								
LDC #xx:8,EXR		R:W 2nd	R:W NEXT							
LDC Rs,CCR		R:W NEXT								
LDC Rs,EXR		R:W NEXT								
LDC @ERs,CCR		R:W 2nd	R:W NEXT	R:W EA						
LDC @ERS,EXR		R:W 2nd	R:W NEXT	R:W EA						
LDC @(d:16,ERs),	CCR)	R:W 2nd	R:W 3rd	R:W NEXT	R:W EA					
LDC @(d:16,ERs),EXR),EXR	R:W 2nd	R:W 3rd	R:W NEXT	R:W EA					
	,CCR	R:W 2nd	R:W 3rd	R:W 4th	R:W 5th	R:W NEXT	R:W EA			
LDC @(d:32,ERs),EXR),EXR	R:W 2nd	R:W 3rd	R:W 4th	R:W 5th	R:W NEXT	R:W EA			
LDC @ERs+,CCR	œ	R:W 2nd	R:W NEXT	Internal operation, R:W EA	R:W EA					
LDC @ERS+,EXR	~	R:W 2nd	R:W NEXT	Internal operation, R:W EA	R:W EA					
1 DC @22:46 CD	0	D.W. 2nd	D-W 2rd	D-W NEVT	D:W EA					
LDC @aa:16,EXR	<u> </u>	R:W 2nd	R:W 3rd	R:W NEXT	R:W EA					
LDC @aa:32,CCR	œ	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	R:W EA				
LDC @aa:32,EXR	~	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	R:W EA				
LDM.L @SP+,		R:W 2nd	R:W:M NEXT	Internal operation,	Internal operation, $\left \text{R:W:M stack (H)}^{*3} \right \text{R:W stack (L)}^{*3}$	R:W stack (L)*3				
(ERn-ERn+1)				1 state						

Instruction	1	2	3	4	2	9	7	8	6
LDM.L @SP+,(ERn-ERn+2)	R:W 2nd	R:W NEXT	Internal operation, 1 state	Internal operation, R:W:M stack $(H)^{*3}$ R:W stack $(L)^{*3}$ 1 state	R:W stack (L)*3				
LDM.L @SP+,(ERn-ERn+3)	R:W 2nd	R:W NEXT	Internal operation,	R:W:M stack (H)*3 R:W stack (L)*3	R:W stack (L)*3				
LDMAC ERS,MACH	Cannot be used	Cannot be used in the H8S/2357 Series	Series .						
LDMAC ERS,MACL									
MAC @ERn+, @ERm+	R:W 2nd	R:W NEXT	R:W EAn	R:W EAm					
MOV.B #xx:8,Rd	R:W NEXT								
MOV.B Rs,Rd	R:W NEXT								
MOV.B @ERs,Rd	R:W NEXT	R:B EA							
MOV.B @(d:16,ERs),Rd	R:W 2nd	R:W NEXT	R:B EA						
MOV.B @(d:32,ERs),Rd	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	R:B EA				
MOV.B @ERs+,Rd	R:W NEXT	Internal operation,	R:B EA						
		1 state							
MOV.B @aa:8,Rd	R:W NEXT	R:B EA							
MOV.B @aa:16,Rd	R:W 2nd	R:W NEXT	R:B EA						
MOV.B @aa:32,Rd	R:W 2nd	R:W 3rd	R:W NEXT	R:B EA					
MOV.B Rs, @ERd	R:W NEXT	W:B EA							
MOV.B Rs, @(d:16,ERd)	R:W 2nd	R:W NEXT	W:B EA						
MOV.B Rs, @(d:32, ERd)	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	W:B EA				
MOV.B Rs,@-ERd	R:W NEXT	Internal operation, W:B EA	W:B EA						
		1 state							
MOV.B Rs,@aa:8	R:W NEXT	W:B EA							
MOV.B Rs,@aa:16	R:W 2nd	R:W NEXT	W:B EA						
MOV.B Rs,@aa:32	R:W 2nd	R:W 3rd	R:W NEXT	W:B EA					
MOV.W #xx:16,Rd	R:W 2nd	R:W NEXT							
MOV.W Rs,Rd	R:W NEXT								
MOV.W @ERs,Rd	R:W NEXT	R:W EA							
MOV.W @(d:16,ERs),Rd	R:W 2nd	R:W NEXT	R:W EA						
MOV.W @(d:32,ERs),Rd	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	R:W EA				
MOV.W @ERs+, Rd	R:W NEXT	Internal operation, R:W EA	R:W EA						
		1 state							
MOV.W @aa:16,Rd	R:W 2nd	R:W NEXT	R:W EA						
MOV.W @aa:32,Rd	R:W 2nd	R:W 3rd	R:W NEXT	R:B EA					
MOV.W Rs,@ERd	R:W NEXT	W:W EA							

Instruction	-	2	3	4	2	9	7	8	6
MOV.W Rs,@(d:16,ERd)	R:W 2nd	R:W NEXT	W:W EA						
MOV.W Rs, @(d:32,ERd)	R:W 2nd	R:W 3rd	R:E 4th	R:W NEXT	W:W EA				
MOV.W Rs,@-ERd	R:W NEXT	Internal operation, W:W EA 1 state	W:W EA						
MOV.W Rs,@aa:16	R:W 2nd	R:W NEXT	W:W EA						
MOV.W Rs,@aa:32	R:W 2nd	R:W 3rd	R:W NEXT	W:W EA					
MOV.L #xx:32,ERd	R:W 2nd	R:W 3rd	R:W NEXT						
MOV.L ERS,ERd	R:W NEXT								
MOV.L @ERS,ERd	R:W 2nd	R:W:M NEXT	R:W:M EA	R:W EA+2					
MOV.L @(d:16,ERs),ERd	R:W 2nd	R:W:M 3rd	R:W NEXT	R:W:M EA	R:W EA+2				
MOV.L @(d:32,ERs),ERd	R:W 2nd	R:W:M 3rd	R:W:M 4th	R:W 5th	R:W NEXT	R:W:M EA	R:W EA+2		
MOV.L @ERs+,ERd	R:W 2nd	R:W:M NEXT	Internal operation,	R:W:M EA	R:W EA+2				
			1 state						
MOV.L @aa:16,ERd	R:W 2nd	R:W:M 3rd	R:W NEXT	R:W:M EA	R:W EA+2				
MOV.L @aa:32,ERd	R:W 2nd	R:W:M 3rd	R:W 4th	R:W NEXT	R:W:M EA	R:W EA+2			
MOV.L ERs,@ERd	R:W 2nd	R:W:M NEXT	W:W:M EA	W:W EA+2					
MOV.L ERs, @ (d:16, ERd)	R:W 2nd	R:W:M 3rd	R:W NEXT	W:W:M EA	W:W EA+2				
MOV.L ERs, @ (d:32, ERd)	R:W 2nd	R:W:M 3rd	R:W:M 4th	R:W 5th	R:W NEXT	W:W:M EA	W:W EA+2		
MOV.L ERs, @-ERd	R:W 2nd	R:W:M NEXT	Internal operation, W:W:M EA	W:W:M EA	W:W EA+2				
			1 state						
MOV.L ERs,@aa:16	R:W 2nd	R:W:M 3rd	R:W NEXT	W:W:M EA	W:W EA+2				
MOV.L ERs,@aa:32	R:W 2nd	R:W:M 3rd	R:W 4th	R:W NEXT	W:W:M EA	W:W EA+2			
MOVFPE @aa:16,Rd	Cannot be use	Cannot be used in the H8S/2357 Series	57 Series						
MOVTPE Rs,@aa:16									
MULXS.B Rs,Rd	R:W 2nd	R:W NEXT	Internal operation, 11 states	on, 11 states					
MULXS.W Rs,ERd	R:W 2nd	R:W NEXT	Internal operation, 19 states	on, 19 states					
MULXU.B Rs,Rd	R:W NEXT	Internal operation, 11 states	on, 11 states						
MULXU.W Rs,ERd	R:W NEXT	Internal operation, 19 states	on, 19 states						
NEG.B Rd	R:W NEXT								
NEG.W Rd	R:W NEXT								
NEG.L ERd	R:W NEXT								
NOP	R:W NEXT								
NOT.B Rd	R:W NEXT								
NOT.W Rd	R:W NEXT								
NOT.L ERd	R:W NEXT								
OR.B #xx:8,Rd	R:W NEXT								
OR.B Rs,Rd	R:W NEXT								

Instruction	-	2	3	4	2	9	7	8	6
OR.W #xx:16,Rd	R:W 2nd	R:W NEXT							
OR.W Rs,Rd	R:W NEXT								
OR.L #xx:32,ERd	R:W 2nd	R:W 3rd	R:W NEXT						
OR.L ERS,ERd	R:W 2nd	R:W NEXT							
ORC #xx:8,CCR	R:W NEXT								
ORC #xx:8,EXR	R:W 2nd	R:W NEXT							
POP.W Rn	R:W NEXT	Internal operation,	R:W EA						
POP.L ERn	R:W 2nd	R:W:M NEXT	Internal operation, R:W:M EA 1 state	R:W:M EA	R:W EA+2				
PUSH.W Rn	R:W NEXT	Internal operation, W:W EA	W:W EA						
PUSH.L ERn	R:W 2nd	R:W:M NEXT	Internal operation, W:W:M EA	W:W:M EA	W:W EA+2				
ROTL.B Rd	R:W NEXT								
ROTL.B #2,Rd	R:W NEXT								
ROTL.W Rd	R:W NEXT								
۶d	R:W NEXT								
	R:W NEXT								
ERd	R:W NEXT								
ROTR.B Rd	R:W NEXT								
ROTR.B #2,Rd	R:W NEXT								
ROTR.W Rd	R:W NEXT								
ROTR.W #2,Rd	R:W NEXT								
ROTR.L ERd	R:W NEXT								
ROTR.L #2,ERd	R:W NEXT								
ROTXL.B Rd	R:W NEXT								
ROTXL.B #2,Rd	R:W NEXT								
ROTXL.W Rd	R:W NEXT								
ROTXL.W #2,Rd	R:W NEXT								
ROTXL.L ERd	R:W NEXT								
ROTXL.L #2,ERd	R:W NEXT								
ROTXR.B Rd	R:W NEXT								
ROTXR.B #2,Rd	R:W NEXT								
ROTXR.W Rd	R:W NEXT								
ROTXR.W #2,Rd	R:W NEXT								
ROTXR.L ERd	R:W NEXT								

Instruction	-	2	8	4	5	9	7	8	6
ROTXR.L #2,ERd	R:W NEXT								
RTE	R:W NEXT	R:W stack (EXR)	R:W stack (H)	R:W stack (L)	Internal operation, R:W*4 1 state	R:W*4			
RTS Advanced	R:W NEXT	R:W:M stack (H) R:W stack (L)	R:W stack (L)	Internal operation, R:W*4 1 state	R:W*4				
SHAL.B Rd	R:W NEXT								
SHAL.B #2,Rd	R:W NEXT								
SHAL.W Rd	R:W NEXT								
SHAL.W #2,Rd	R:W NEXT								
SHAL.L ERd	R:W NEXT								
SHAL.L #2,ERd	R:W NEXT								
SHAR.B Rd	R:W NEXT								
SHAR.B #2,Rd	R:W NEXT								
SHAR.W Rd	R:W NEXT								
SHAR.W #2,Rd	R:W NEXT								
SHAR.L ERd	R:W NEXT								
SHAR.L #2,ERd	R:W NEXT								
SHLL.B Rd	R:W NEXT								
SHLL.B #2,Rd	R:W NEXT								
SHLL.W Rd	R:W NEXT								
SHLL.W #2,Rd	R:W NEXT								
SHLL.L ERd	R:W NEXT								
SHLL.L #2,ERd	R:W NEXT								
SHLR.B Rd	R:W NEXT								
SHLR.B #2,Rd	R:W NEXT								
SHLR.W Rd	R:W NEXT								
SHLR.W #2,Rd	R:W NEXT								
SHLR.L ERd	R:W NEXT								
SHLR.L #2,ERd	R:W NEXT								
SLEEP	R:W NEXT	Internal operation:M							
STC CCR, Rd	R:W NEXT								
STC EXR,Rd	R:W NEXT								
STC CCR, @ERd	R:W 2nd	R:W NEXT	W:W EA						
STC EXR, @ERd		R:W NEXT	W:W EA						
STC CCR, @(d:16,ERd)	R:W 2nd	R:W 3rd	R:W NEXT	W:W EA					

Instruction	-	2	က	4	2	9	2	8	6
STC EXR, @(d:16,ERd)	R:W 2nd	R:W 3rd	R:W NEXT	W:W EA					
STC CCR, @(d:32,ERd)	R:W 2nd	R:W 3rd	R:W 4th	R:W 5th	R:W NEXT	W:W EA			
STC EXR, @ (d:32, ERd)	R:W 2nd	R:W 3rd	R:W 4th	R:W 5th	R:W NEXT	W:W EA			
STC CCR, @-ERd	R:W 2nd	R:W NEXT	Internal operation, W:W EA 1 state	W:W EA					
STC EXR,@-ERd	R:W 2nd	R:W NEXT	Internal operation, W:W EA 1 state	W:W EA					
STC CCR, @aa:16	R:W 2nd	R:W 3rd	R:W NEXT	W:W EA					
STC EXR,@aa:16	R:W 2nd	R:W 3rd	R:W NEXT	W:W EA					
STC CCR, @aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	W:W EA				
STC EXR,@aa:32	R:W 2nd	R:W 3rd	R:W 4th	R:W NEXT	W:W EA				
STM.L(ERn-ERn+1),@-SP	R:W 2nd	R:W:M NEXT	Internal operation, 1 state	Internal operation, $\begin{tabular}{ll} W:W:M stack (H)^{*3} & W:W stack (L)^{*3} \\ 1 state \end{tabular}$	W:W stack (L)*3				
STM.L(ERn-ERn+2),@-SP	R:W 2nd	R:W:M NEXT	Internal operation,	Internal operation, $\left \text{W:W:M stack (H)}^{*3} \right \text{W:W stack (L)}^{*3}$	W:W stack (L)*3				
			1 state						
STM.L(ERn-ERn+3),@-SP	R:W 2nd	R:W:M NEXT	Internal operation, 1 state	Internal operation, $\begin{tabular}{ll} W:W:M stack (H)^{*3} & W:W stack (L)^{*3} \\ 1 state \end{tabular}$	W:W stack (L)*3				
STMAC MACH, ERd	Cannot be use	Cannot be used in the H8S/2357 Series	357 Series						
STMAC MACL, ERd									
	R:W NEXT								
,Rd	R:W 2nd	R:W NEXT							
SUB.W Rs,Rd	R:W NEXT								
Sd Sd	R:W 2nd	R:W 3rd	R:W NEXT						
	R:W NEXT								
۶d	R:W NEXT								
2d	R:W NEXT								
SUBX Rs,Rd	R:W NEXT								
TAS @ERd*8	R:W 2nd	R:W NEXT	R:B:M EA	W:B EA					
TRAPA #x:2 Advanced	R:W NEXT	Internal operation, 1 state	W:W stack (L)	W:W stack (H)	W:W stack (EXR) R:W:M VEC	R:W:M VEC	R:W VEC+2	Internal operation, R:W*8 1 state	R:W*8
XOR.B #xx8,Rd	R:W NEXT								
	R:W NEXT								
,Rd	R:W 2nd	R:W NEXT							
	R:W NEXT								
XOR.L #xx:32,ERd	R:W 2nd	R:W 3rd	R:W NEXT						

Instruction	on	1	2	3	4	2	9	2	8	6
XOR.L ERS,ERd	p;	R:W 2nd	W 2nd R:W NEXT							
XORC #xx:8,CCR	CR	R:W NEXT								
XORC #xx:8,EXR	XR	R:W 2nd	V 2nd R:W NEXT							
Reset exception	Advanced	R:W VEC	keset exception Advanced R:W VEC R:W VEC+2 Internal operation, R:W*5	Internal operation,	R:W*5					
handling				1 state						
Interrupt exception Advanced R:W	Advanced	R:W*6	Internal operation,	itemal operation, W:W stack (L) W:W stack (H) W:W stack (EXR) R:W:M VEC R:W VEC+2 Internal operation, R:W**7	W:W stack (H)	W:W stack (EXR)	R:W:M VEC	R:W VEC+2	Internal operation,	R:W*7
handling			1 state						1 state	

EAs is the contents of ER5. EAd is the contents of ER6. Notes:

EAs is the contents of ER5. EAd is the contents of ER6. Both registers are incremented by 1 after execution of the instruction. n is the initial value of R4L or R4. If n = 0, these bus cycles are not executed. ← ~;

Repeated two times to save or restore two registers, three times for three registers, or four times for four registers. Start address after return. 6. 4. 7. 0.

Start address of the program.

Prefetch address, equal to two plus the PC value pushed onto the stack. In recovery from sleep mode or software standby mode the read operation is replaced by an internal operation.

Start address of the interrupt-handling routine.

Only register ER0, ER1, ER4, or ER5 should be used when using the TAS instruction. ۸. %

A.6 Condition Code Modification

This section indicates the effect of each CPU instruction on the condition code. The notation used in the table is defined below.

$$m = \left\{ \begin{array}{l} 31 \text{ for longword operands} \\ \\ 15 \text{ for word operands} \\ \\ 7 \text{ for byte operands} \end{array} \right.$$

Si The i-th bit of the source operand

Di The i-th bit of the destination operand

Ri The i-th bit of the result

Dn The specified bit in the destination operand

Not affected

1 Modified according to the result of the instruction (see definition)

0 Always cleared to 0

1 Always set to 1

* Undetermined (no guaranteed value)

Z' Z flag before instruction execution

C' C flag before instruction execution

Table A-7 Condition Code Modification

Instruction	н	N	Z	٧	С	Definition
ADD	‡	\$	‡	‡	‡	$H = Sm-4 \cdot Dm-4 + Dm-4 \cdot \overline{Rm-4} + Sm-4 \cdot \overline{Rm-4}$
						N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
						$V = Sm \cdot Dm \cdot \overline{Rm} + \overline{Sm} \cdot \overline{Dm} \cdot Rm$
						$C = Sm \cdot Dm + Dm \cdot \overline{Rm} + Sm \cdot \overline{Rm}$
ADDS	_	_	_	_	_	
ADDX	‡	‡	‡	‡	‡	$H = Sm4 \cdot Dm4 + Dm4 \cdot \overline{Rm4} + Sm4 \cdot \overline{Rm4}$
						N = Rm
						$Z = Z' \cdot \overline{Rm} \cdot \cdots \cdot \overline{R0}$
						$V = Sm \cdot Dm \cdot \overline{Rm} + \overline{Sm} \cdot \overline{Dm} \cdot Rm$
						$C = Sm \cdot Dm + Dm \cdot \overline{Rm} + Sm \cdot \overline{Rm}$
AND	_	‡	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \dots \cdot \overline{R0}$
ANDC	\$	‡	\$	‡	‡	Stores the corresponding bits of the result.
						No flags change when the operand is EXR.
BAND	_	_	_	_	‡	$C = C' \cdot Dn$
Bcc	_	_	—	_	_	
BCLR	_	_	_	_	_	
BIAND	_	_	_	_	‡	$C = C' \cdot \overline{Dn}$
BILD	_	_	—	_	‡	$C = \overline{Dn}$
BIOR	_	_	_	_	‡	$C = C' + \overline{Dn}$
BIST	_	_	_	_	_	
BIXOR	_	_	_	_	‡	$C = C' \cdot Dn + \overline{C'} \cdot \overline{Dn}$
BLD	_	_	_	_	‡	C = Dn
BNOT	_	_	_	_	_	
BOR	_	_	_	_	‡	C = C' + Dn
BSET	_	_	_	_	_	
BSR	_	_	_	_	_	
BST	_	_	_	_	_	
BTST	_	_	‡	_	_	$Z = \overline{Dn}$
BXOR	_	_	_	_	‡	$C = C' \cdot \overline{Dn} + \overline{C'} \cdot Dn$
CLRMAC						Cannot be used in the H8S/2357 Series

Instruction	Н	N	Z	٧	С	Definition
CMP	‡	\$	‡	‡	‡	$H = Sm-4 \cdot \overline{Dm-4} + \overline{Dm-4} \cdot Rm-4 + Sm-4 \cdot Rm-4$
						N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
						$V = \overline{Sm} \cdot Dm \cdot \overline{Rm} + Sm \cdot \overline{Dm} \cdot Rm$
						$C = Sm \cdot \overline{Dm} + \overline{Dm} \cdot Rm + Sm \cdot Rm$
DAA	*	‡	‡	*	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
						C: decimal arithmetic carry
DAS	*	1	‡	*	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
						C: decimal arithmetic borrow
DEC	_	‡	‡	‡	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - \overline{1} \cdot \cdots \cdot \overline{R0}$
						$V = Dm \cdot \overline{Rm}$
DIVXS	_	\$	‡	_	_	$N = Sm \cdot \overline{Dm} + \overline{Sm} \cdot Dm$
						$Z = \overline{Sm} \cdot \overline{Sm-1} \cdot \dots \cdot \overline{S0}$
DIVXU	_	‡	1	_	_	N = Sm
						$Z = \overline{Sm} \cdot \overline{Sm-1} \cdot \dots \cdot \overline{S0}$
EEPMOV	_		_	_	_	
EXTS	_	\$	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
EXTU	_	0	1	0	_	$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
INC	_	‡	1	‡	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \dots \cdot \overline{R0}$
						$V = \overline{Dm} \cdot Rm$
JMP	_	_	_	_	_	
JSR	_		_	_	_	
LDC	‡	‡	‡	‡	‡	Stores the corresponding bits of the result.
						No flags change when the operand is EXR.
LDM	_	_	_	_	_	
LDMAC						Cannnot be used in the H8S/2357 Series
MAC						

Instruction	Н	N	Z	٧	С	Definition
MOV	_	\$	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \cdots \cdot \overline{R0}$
MOVFPE						Can not be used in the H8S/2357 Series
MOVTPE						
MULXS	_	‡	‡	_	_	N = R2m
						$Z = \overline{R2m} \cdot \overline{R2m-1} \cdot \cdots \cdot \overline{R0}$
MULXU	_	_	_	_	_	
NEG	1	‡	‡	1	‡	H = Dm-4 + Rm-4
						N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
						$V = Dm \cdot Rm$
						C = Dm + Rm
NOP	_	_	_	_	_	
NOT	_	‡	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \cdots \cdot \overline{R0}$
OR	_	‡	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \dots \cdot \overline{R0}$
ORC	\	‡	‡	1	\	Stores the corresponding bits of the result.
						No flags change when the operand is EXR.
POP	_	‡	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
PUSH	_	‡	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
ROTL	_	‡	‡	0	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
						C = Dm (1-bit shift) or $C = Dm-1$ (2-bit shift)
ROTR	_	\$	‡	0	\(\)	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \cdots \cdot \overline{R0}$
						C = D0 (1-bit shift) or $C = D1$ (2-bit shift)

Instruction	н	N	z	٧	С	Definition
ROTXL	_	‡		0	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
						C = Dm (1-bit shift) or C = Dm-1 (2-bit shift)
ROTXR	_	‡	‡	0	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
						C = D0 (1-bit shift) or $C = D1$ (2-bit shift)
RTE	‡	‡	‡	\$	‡	Stores the corresponding bits of the result.
RTS	_	_	_	_	_	
SHAL	_	‡	‡	‡	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
						$V = \overline{Dm \cdot Dm - 1 + \overline{Dm} \cdot \overline{Dm - 1}} $ (1-bit shift)
						$V = \overline{Dm \cdot Dm - 1 \cdot Dm - 2 \cdot \overline{Dm} \cdot \overline{Dm - 1} \cdot \overline{Dm - 2}} (2-bit shift)$
						C = Dm (1-bit shift) or C = Dm-1 (2-bit shift)
SHAR	_	‡	‡	0	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \cdots \cdot \overline{R0}$
						C = D0 (1-bit shift) or $C = D1$ (2-bit shift)
SHLL	_	‡	\$	0	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \cdots \cdot \overline{R0}$
						C = Dm (1-bit shift) or $C = Dm-1$ (2-bit shift)
SHLR	_	0	‡	0	‡	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm} - 1 \cdot \dots \cdot \overline{R0}$
						C = D0 (1-bit shift) or $C = D1$ (2-bit shift)
SLEEP	_	_	_	_	_	
STC	_	_	_	_	_	
STM	_	_	_	_	_	
STMAC						Cannot be used in the H8S/2357 Series

Instruction	Н	N	Z	٧	С	Definition
SUB	‡	\$	‡	‡	\$	$H = Sm-4 \cdot \overline{Dm-4} + \overline{Dm-4} \cdot Rm-4 + Sm-4 \cdot Rm-4$
						N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \cdots \cdot \overline{R0}$
						$V = \overline{Sm} \cdot Dm \cdot \overline{Rm} + Sm \cdot \overline{Dm} \cdot Rm$
						$C = Sm \cdot \overline{Dm} + \overline{Dm} \cdot Rm + Sm \cdot Rm$
SUBS	_	_	_	_	_	
SUBX	\$	\$	‡	1	‡	$H = Sm-4 \cdot \overline{Dm-4} + \overline{Dm-4} \cdot Rm-4 + Sm-4 \cdot Rm-4$
						N = Rm
						$Z = Z' \cdot \overline{Rm} \cdot \dots \cdot \overline{R0}$
						$V = \overline{Sm} \cdot Dm \cdot \overline{Rm} + Sm \cdot \overline{Dm} \cdot Rm$
						$C = Sm \cdot \overline{Dm} + \overline{Dm} \cdot Rm + Sm \cdot Rm$
TAS	_	\$	‡	0	_	N = Dm
						$Z = \overline{Dm} \cdot \overline{Dm-1} \cdot \cdots \cdots \cdot \overline{D0}$
TRAPA	_	_	_	_	_	
XOR	_	‡	‡	0	_	N = Rm
						$Z = \overline{Rm} \cdot \overline{Rm-1} \cdot \dots \cdot \overline{R0}$
XORC	‡	‡	1	1	‡	Stores the corresponding bits of the result.
						No flags change when the operand is EXR.

Appendix B Internal I/O Register

B.1 Addresses

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'F800	MRA	SM1	SM0	DM1	DM0	MD1	MD0	DTS	Sz	DTC	16/32*1
to H'FBFF	SAR									-	bit
	MRB	CHNE	DISEL	_	_	_	_	_	_		
	DAR	-									
	CRA										
	CRB										
H'FE80	TCR3	CCLR2	CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0	TPU3	16 bit
H'FE81	TMDR3	_	_	BFB	BFA	MD3	MD2	MD1	MD0		
H'FE82	TIOR3H	IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0		
H'FE83	TIOR3L	IOD3	IOD2	IOD1	IOD0	IOC3	IOC2	IOC1	IOC0		
H'FE84	TIER3	TTGE	_	_	TCIEV	TGIED	TGIEC	TGIEB	TGIEA		
H'FE85	TSR3	_	_	_	TCFV	TGFD	TGFC	TGFB	TGFA		
H'FE86	TCNT3										
H'FE87	_										
H'FE88	TGR3A										
H'FE89											
H'FE8A	TGR3B										
H'FE8B											
H'FE8C	TGR3C										
H'FE8D											
H'FE8E	TGR3D										
H'FE8F											

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FE90	TCR4	_	CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0	TPU4	16 bit
H'FE91	TMDR4	_	_	_	_	MD3	MD2	MD1	MD0		
H'FE92	TIOR4	IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0		
H'FE94	TIER4	TTGE	_	TCIEU	TCIEV	_	_	TGIEB	TGIEA		
H'FE95	TSR4	TCFD	_	TCFU	TCFV	_	_	TGFB	TGFA		
H'FE96	TCNT4										
H'FE97											
H'FE98	TGR4A										
H'FE99	_										
H'FE9A	TGR4B										
H'FE9B											
H'FEA0	TCR5	_	CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0	TPU5	16 bit
H'FEA1	TMDR5	_	_	_	_	MD3	MD2	MD1	MD0		
H'FEA2	TIOR5	IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0		
H'FEA4	TIER5	TTGE	_	TCIEU	TCIEV	_	_	TGIEB	TGIEA		
H'FEA5	TSR5	TCFD	_	TCFU	TCFV	_	_	TGFB	TGFA		
H'FEA6	TCNT5										
H'FEA7											
H'FEA8	TGR5A										
H'FEA9											
H'FEAA	TGR5B										
H'FEAB											
H'FEB0	P1DDR	P17DDR	P16DDR	P15DDR	P14DDR	P13DDR	P12DDR	P11DDR	P10DDR	Port	8 bit
H'FEB1	P2DDR	P27DDR	P26DDR	P25DDR	P24DDR	P23DDR	P22DDR	P21DDR	P20DDR		
H'FEB2	P3DDR	_	_	P35DDR	P34DDR	P33DDR	P32DDR	P31DDR	P30DDR		
H'FEB4	P5DDR	_	_	_	_	P53DDR	P52DDR	P51DDR	P50DDR		
H'FEB5	P6DDR	P67DDR	P66DDR	P65DDR	P64DDR	P63DDR	P62DDR	P61DDR	P60DDR		
H'FEB9	PADDR	PA7DDR	PA6DDR	PA5DDR	PA4DDR	PA3DDR	PA2DDR	PA1DDF	R PA0DDR		
H'FEBA	PBDDR*	² PB7DDR	PB6DDR	PB5DDR	PB4DDR	PB3DDR	PB2DDR	PB1DDF	R PB0DDR		
H'FEBB	PCDDR*	² PC7DDR	PC6DDR	PC5DDR	PC4DDR	R PC3DDR	PC2DDR	PC1DDF	R PC0DDR		
H'FEBC	PDDDR*	² PD7DDR	PD6DDR	PD5DDR	PD4DDR	R PD3DDR	PD2DDR	PD1DDF	R PD0DDR		
H'FEBD	PEDDR	PE7DDR	PE6DDR	PE5DDR	PE4DDR	PE3DDR	PE2DDR	PE1DDF	R PE0DDR		
H'FEBE	PFDDR	PF7DDR	PF6DDR	PF5DDR	PF4DDR	PF3DDR	PF2DDR	PF1DDR	PF0DDR		
H'FEBF	PGDDR	_	_	_	PG4DDF	R PG3DDF	R PG2DDF	RPG1DDF	RPG0DDR		

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FEC4	IPRA	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0	Interrupt	8 bit
H'FEC5	IPRB	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0	controller	
H'FEC6	IPRC	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FEC7	IPRD	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FEC8	IPRE	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FEC9	IPRF	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FECA	IPRG	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FECB	IPRH	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FECC	IPRI	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FECD	IPRJ	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FECE	IPRK	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0		
H'FED0	ABWCR	ABW7	ABW6	ABW5	ABW4	ABW3	ABW2	ABW1	ABW0	Bus controller	8 bit
H'FED1	ASTCR	AST7	AST6	AST5	AST4	AST3	AST2	AST1	AST0		
H'FED2	WCRH	W71	W70	W61	W60	W51	W50	W41	W40		
H'FED3	WCRL	W31	W30	W21	W20	W11	W10	W01	W00		
H'FED4	BCRH	ICIS1	ICIS0	BRSTRM	BRSTS1	BRSTS0	RMTS2	RMTS1	RMST0		
H'FED5	BCRL	BRLE	BREQOE	EAE	LCASS	DDS	_	WDBE	WAITE		
H'FED6	MCR	TPC	BE	RCDM	CW2	MXC1	MXC0	RLW1	RLW0		
H'FED7	DRAMCF	RFSHE	RCW	RMODE	CMF	CMIE	CKS2	CKS1	CKS0		
H'FED8	RTCNT										
H'FED9	RTCOR								_		
H'FEDB*	7 RAMER	_	_	_	_	_	RAMS	RAM1	RAM0		
H'FEDB**	^{8,} RAMER	_	_	_	_	RAMS	RAM2	RAM1	RAM0		
H'FEE0	MAR0AH		_	_	_	_		_	_	DMAC	16 bit
H'FEE1											
H'FEE2	MAR0AL										
H'FEE3											
H'FEE4	IOAR0A										
H'FEE5											
H'FEE6	ETCR0A										
H'FEE7											
H'FEE8	MAR0BH		_	_	_	_	_	_	_		
H'FEE9											
H'FEEA	MAR0BL										
H'FEEB											
H'FEEC	IOAR0B										
H'FEED											
H'FEEE	ETCR0B										
H'FEEF											

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FEF0	MAR1AH	_	_	_	_	_	_	_	_	DMAC	16 bit
H'FEF1	_	-									
H'FEF2	MAR1AL								_		
H'FEF3	_										
H'FEF4	IOAR1A										
H'FEF5											
H'FEF6	ETCR1A										
H'FEF7											
H'FEF8	MAR1BH		_	_	_	_	_	_			
H'FEF9											
H'FEFA	MAR1BL										
H'FEFB											
H'FEFC	IOAR1B										
H'FEFD											
H'FEFE	ETCR1B										
H'FEFF											
H'FF00	DMAWE	₹—	_	_	_	WE1B	WE1A	WE0B	WE0A		8 bit
H'FF01	DMATCR	!—	_	TEE1	TEE0	_	_	_	_		
H'FF02	DMACR0A	DTSZ	DTID	RPE	DTDIR	DTF3	DTF2	DTF1	DTF0	Short address mode	16 bit
		DTSZ	SAID	SAIDE	BLKDIR	BLKE	_	_	_	Full address mode	_
H'FF03	DMACR0B	DTSZ	DTID	RPE	DTDIR	DTF3	DTF2	DTF1	DTF0	Short address mode	
		_	DAID	DAIDE	_	DTF3	DTF2	DTF1	DTF0	Full address mode	
H'FF04	DMACR1A	DTSZ	DTID	RPE	DTDIR	DTF3	DTF2	DTF1	DTF0	Short address mode	
		DTSZ	SAID	SAIDE	BLKDIR	BLKE	_	_	_	Full address mode	_
H'FF05	DMACR1B	DTSZ	DTID	RPE	DTDIR	DTF3	DTF2	DTF1	DTF0	Short address mode	_
		_	DAID	DAIDE	_	DTF3	DTF2	DTF1	DTF0	Full address mode	_
H'FF06	DMABCRH	FAE1	FAE0	SAE1	SAE0	DTA1B	DTA1A	DTA0B	DTA0A	Short address mode	_
		FAE1	FAE0	_	_	DTA1	_	DTA0	_	Full address mode	_
H'FF07	DMABCRL	DTE1B	DTE1A	DTE0B	DTE0A	DTIE1B	DTIE1A	DTIE0B	DTIE0A	Short address mode	_
		DTME1	DTE1	DTME0	DTE0	DTIE1B	DTIE1A	DTIE0B	DTIE0A	Full address mode	<u> </u>

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FF2C	ISCRH	IRQ7SCB	IRQ7SCA	IRQ6SCB	IRQ6SCA	IRQ5SCB	IRQ5SCA	IRQ4SCB	IRQ4SCA	Interrupt	8 bit
H'FF2D	ISCRL	IRQ3SCB	IRQ3SCA	IRQ2SCB	IRQ2SCA	IRQ1SCB	IRQ1SCA	IRQ0SCB	IRQ0SCA	controller	
H'FF2E	IER	IRQ7E	IRQ6E	IRQ5E	IRQ4E	IRQ3E	IRQ2E	IRQ1E	IRQ0E		
H'FF2F	ISR	IRQ7F	IRQ6F	IRQ5F	IRQ4F	IRQ3F	IRQ2F	IRQ1F	IRQ0F		
H'FF30 to	DTCER	DTCE7	DTCE6	DTCE5	DTCE4	DTCE3	DTCE2	DTCE1	DTCE0	DTC	8 bit
H'FF37	DTVECR	SWDTE	DTVEC6	DTVEC5	DTVEC4	DTVEC3	DTVEC2	DTVEC1	DTVEC0		
H'FF38	SBYCR	SSBY	STS2	STS1	STS0	OPE	_	_	_	Power-down mode	8 bit
H'FF39	SYSCR	_	_	INTM1	INTM0	NMIEG	_	_	RAME	MCU	8 bit
H'FF3A	SCKCR	PSTOP	-	-	-	-	SCK2	SCK1	SCK0	Clock pulse generator	8 bit
H'FF3B	MDCR	_	_	_	_	_	MDS2	MDS1	MDS0	MCU	8 bit
H'FF3C	MSTPCRH	MSTP15	MSTP14	MSTP13	MSTP12	MSTP11	MSTP10	MSTP9	MSTP8	Power-down	8 bit
H'FF3D	MSTPCRL	MSTP7	MSTP6	MSTP5	MSTP4	MSTP3	MSTP2	MSTP1	MSTP0	mode	
H'FF42	SYSCR2 * 7, * 8, * 9, * 1		_	_	_	FLSHE	_	_	_	MCU	8 bit
H'FF44	Reserved	_	_	_	_	_	_	_	_	Reserved	_
H'FF45	Reserved	_	_	_	_	_	_	_	_	Reserved	_
H'FF46	PCR	G3CMS1	G3CMS0	G2CMS1	G2CMS0	G1CMS1	G1CMS0	G0CMS1	G0CMS0	PPG	8 bit
H'FF47	PMR	G3INV	G2INV	G1INV	G0INV	G3NOV	G2NOV	G1NOV	G0NOV		
H'FF48	NDERH	NDER15	NDER14	NDER13	NDER12	NDER11	NDER10	NDER9	NDER8		
H'FF49	NDERL	NDER7	NDER6	NDER5	NDER4	NDER3	NDER2	NDER1	NDER0		
H'FF4A	PODRH	POD15	POD14	POD13	POD12	POD11	POD10	POD9	POD8		
H'FF4B	PODRL	POD7	POD6	POD5	POD4	POD3	POD2	POD1	POD0		
H'FF4C*3	NDRH	NDR15	NDR14	NDR13	NDR12	NDR11	NDR10	NDR9	NDR8		
H'FF4D*3	NDRL	NDR7	NDR6	NDR5	NDR4	NDR3	NDR2	NDR1	NDR0		
H'FF4E*3	NDRH	_	_	_	_	NDR11	NDR10	NDR9	NDR8		
H'FF4F*3	NDRL	_	_	_	_	NDR3	NDR2	NDR1	NDR0		

	Register				-		-				Data Bus
(low)	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Width
H'FF50	PORT1	P17	P16	P15	P14	P13	P12	P11	P10	Port	8 bit
H'FF51	PORT2	P27	P26	P25	P24	P23	P22	P21	P20		
H'FF52	PORT3	_	_	P35	P34	P33	P32	P31	P30		
H'FF53	PORT4	P47	P46	P45	P44	P43	P42	P41	P40		
H'FF54	PORT5	_	_	_	_	P53	P52	P51	P50		
H'FF55	PORT6	P67	P66	P65	P64	P63	P62	P61	P60		
H'FF59	PORTA	PA7	PA6	PA5	PA4	PA3	PA2	PA1	PA0		
H'FF5A	PORTB*2	PB7	PB6	PB5	PB4	PB3	PB2	PB1	PB0		
H'FF5B	PORTC*	PC7	PC6	PC5	PC4	PC3	PC2	PC1	PC0		
H'FF5C	PORTD*	PD7	PD6	PD5	PD4	PD3	PD2	PD1	PD0		
H'FF5D	PORTE	PE7	PE6	PE5	PE4	PE3	PE2	PE1	PE0		
H'FF5E	PORTF	PF7	PF6	PF5	PF4	PF3	PF2	PF1	PF0		
H'FF5F	PORTG	_	_	_	PG4	PG3	PG2	PG1	PG0		
H'FF60	P1DR	P17DR	P16DR	P15DR	P14DR	P13DR	P12DR	P11DR	P10DR		
H'FF61	P2DR	P27DR	P26DR	P25DR	P24DR	P23DR	P22DR	P21DR	P20DR		
H'FF62	P3DR	_	_	P35DR	P34DR	P33DR	P32DR	P31DR	P30DR		
H'FF64	P5DR	_	_	_	_	P53DR	P52DR	P51DR	P50DR		
H'FF65	P6DR	P67DR	P66DR	P65DR	P64DR	P63DR	P62DR	P61DR	P60DR		
H'FF69	PADR	PA7DR	PA6DR	PA5DR	PA4DR	PA3DR	PA2DR	PA1DR	PA0DR		
H'FF6A	PBDR*2	PB7DR	PB6DR	PB5DR	PB4DR	PB3DR	PB2DR	PB1DR	PB0DR		
H'FF6B	PCDR*2	PC7DR	PC6DR	PC5DR	PC4DR	PC3DR	PC2DR	PC1DR	PC0DR		
H'FF6C	PDDR*2	PD7DR	PD6DR	PD5DR	PD4DR	PD3DR	PD2DR	PD1DR	PD0DR		
H'FF6D	PEDR	PE7DR	PE6DR	PE5DR	PE4DR	PE3DR	PE2DR	PE1DR	PE0DR		
H'FF6E	PFDR	PF7DR	PF6DR	PF5DR	PF4DR	PF3DR	PF2DR	PF1DR	PF0DR		
H'FF6F	PGDR	_	_	_	PG4DR	PG3DR	PG2DR	PG1DR	PG0DR		
H'FF70	PAPCR*2	PA7PCR	PA6PCR	PA5PCR	PA4PCR	PA3PCR	PA2PCR	PA1PCR	PA0PCR		
H'FF71	PBPCR*2	PB7PCR	PB6PCR	PB5PCR	PB4PCR	PB3PCR	PB2PCR	PB1PCR	PB0PCR		
H'FF72	PCPCR*	PC7PCR	PC6PCR	PC5PCR	PC4PCR	PC3PCR	PC2PCR	PC1PCR	PC0PCR		
H'FF73	PDPCR*	PD7PCR	PD6PCR	PD5PCR	PD4PCR	PD3PCR	PD2PCR	PD1PCR	PD0PCR		
H'FF74	PEPCR*2	PE7PCR	PE6PCR	PE5PCR	PE4PCR	PE3PCR	PE2PCR	PE1PCR	PE0PCR		
H'FF76	P3ODR	_	_	P35ODR	P34ODR	P33ODR	P32ODR	P31ODR	P30ODR		
H'FF77	PAODR*	PA7ODR	PA6ODR	PA5ODR	PA4ODR	PA3ODR	PA2ODR	PA10DR	PA0ODR		

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FF78	SMR0	C/Ā/ GM* ⁴	CHR	PE	O/Ē	STOP	MP	CKS1	CKS0	SCI0, Smart card	8 bit
H'FF79	BRR0									interface 0	
H'FF7A	SCR0	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0	=	
H'FF7B	TDR0									-	
H'FF7C	SSR0	TDRE	RDRF	ORER	FER/ ERS* ⁵	PER	TEND	MPB	MPBT	•	
H'FF7D	RDR0									•	
H'FF7E	SCMR0	_	_	_	_	SDIR	SINV	_	SMIF	•	
H'FF80	SMR1	C/Ā/ GM* ⁴	CHR	PE	O/Ē	STOP	MP	CKS1	CKS0	SCI1, Smart card	8 bit
H'FF81	BRR1									interface 1	
H'FF82	SCR1	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0		
H'FF83	TDR1										
H'FF84	SSR1	TDRE	RDRF	ORER	FER/ ERS* ⁵	PER	TEND	MPB	MPBT		
H'FF85	RDR1										
H'FF86	SCMR1	_	_	_	_	SDIR	SINV	_	SMIF		
H'FF88	SMR2	C/Ā/ GM* ⁴	CHR	PE	O/Ē	STOP	MP	CKS1	CKS0	SCI2, Smart card	8 bit
H'FF89	BRR2									interface 2	
H'FF8A	SCR2	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0		
H'FF8B	TDR2									_	
H'FF8C	SSR2	TDRE	RDRF	ORER	FER/ ERS* ⁵	PER	TEND	MPB	MPBT		
H'FF8D	RDR2										
H'FF8E	SCMR2	_	_	_	_	SDIR	SINV	_	SMIE	•	
H'FF90	ADDRAH	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	A/D converter	8 bit
H'FF91	ADDRAL	AD1	AD0	_	_	_	_	_	_	•	
H'FF92	ADDRBH	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	-	
H'FF93	ADDRBL	AD1	AD0	_	_	_	_	_	_	•	
H'FF94	ADDRCH	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2		
H'FF95	ADDRCL	AD1	AD0	_	_	_	_	_	_		
H'FF96	ADDRDH	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	<u>.</u>	
H'FF97	ADDRDL	AD1	AD0			_					
H'FF98	ADCSR	ADF	ADIE	ADST	SCAN	CKS	_	CH1	CH0		
H'FF99	ADCR	TRGS1	TRGS0	_	_	_	_	_	_		

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FFA4	DADR0									D/A converter	8 bit
H'FFA5	DADR1										
H'FFA6	DACR	DAOE1	DAOE0	DAE	_	_	_	_	_		
H'FFAC	Reserved	I —	_	_	_	_	_	_	_	Reserved	_
H'FFB0	TCR0	CMIEB	CMIEA	OVIE	CCLR1	CCLR0	CKS2	CKS1	CKS0	8-bit timer	16 bit
H'FFB1	TCR1	CMIEB	CMIEA	OVIE	CCLR1	CCLR0	CKS2	CKS1	CKS0	channel 0, 1	
H'FFB2	TCSR0	CMFB	CMFA	OVF	ADTE	OS3	OS2	OS1	OS0		
H'FFB3	TCSR1	CMFB	CMFA	OVF	_	OS3	OS2	OS1	OS0		
H'FFB4	TCORA0										
H'FFB5	TCORA1										
H'FFB6	TCORB0										
H'FFB7	TCORB1										
H'FFB8	TCNT0										
H'FFB9	TCNT1										
H'FFBC	TCSR	OVF	WT/ĪT	TME	_	_	CKS2	CKS1	CKS0	WDT	16 bit
(read)											
H'FFBD	TCNT										
(read)											
H'FFBF (read)	RSTCSR	WOVF	RSTE	RSTS*6	_	_	_	_	_		
H'FFC0	TSTR	_	_	CST5	CST4	CST3	CST2	CST1	CST0	TPU	16 bit
H'FFC1	TSYR			SYNC5	SYNC4	SYNC3	SYNC2	SYNC1	SYNC0	11 0	10 Dit
-	FLMCR1		SWE	_	_	EV	PV	E	P	FLASH	8 bit
-	FLMCR2		_	_		_	_	ESU	PSU	(2357F-ZTAT)	O DIL
H'FFCA*		- LLK						EB9	EB8	,	
H'FFCB*		EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0		
-	FLMCR1		SWE	ESU	PSU	EV	PV	E	P	FLASH	8 bit
-	FLMCR2			L30		LV			_	(2398F-ZTAT)	O DIL
H'FFCA*		EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0	,	
H'FFCB*		_	_	_	_	EB11	EB10	EB9	EB8		
-	FLMCR1		SWE1	ESU1	PSU1	EV1	PV1	E1	P1	FLASH	8 bit
	FLMCR2		SWE2	ESU2	PSU2	EV2	PV2	E2	P2	(2395F-ZTAT)	O DIL
H'FFCA*		EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0		
H'FFCB*		_	_	EB13	EB12	EB11	EB10	EB9	EB8		
	°FLMCR1		SWE1	ESU1	PSU1	EV1	PV1	E1	P1	FLASH	8 bit
-	°FLMCR2		SWE2	ESU2			PV1	E2	P2	(2396F-ZTAT)	O DIL
H'FFCA*		EB7	EB6	EB5	PSU2 EB4	EV2	EB2		EB0	, ,	1
						EB3		EB1			
H'FFCB*	CDKZ	EB15	EB14	EB13	EB12	EB11	EB10	EB9	EB8		

Address (low)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name	Data Bus Width
H'FFD0	TCR0	CCLR2	CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0	TPU0	16 bit
H'FFD1	TMDR0	_	_	BFB	BFA	MD3	MD2	MD1	MD0		
H'FFD2	TIOR0H	IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0		
H'FFD3	TIOR0L	IOD3	IOD2	IOD1	IOD0	IOC3	IOC2	IOC1	IOC0		
H'FFD4	TIER0	TTGE	_	_	TCIEV	TGIED	TGIEC	TGIEB	TGIEA		
H'FFD5	TSR0	_	_	_	TCFV	TGFD	TGFC	TGFB	TGFA		
H'FFD6	TCNT0										
H'FFD7											
H'FFD8	TGR0A										
H'FFD9	-										
H'FFDA	TGR0B										
H'FFDB	_										
H'FFDC	TGR0C										
H'FFDD	-										
H'FFDE	TGR0D										
H'FFDF	_										
H'FFE0	TCR1	_	CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0	TPU1	16 bit
H'FFE1	TMDR1	_	_	_	_	MD3	MD2	MD1	MD0		
H'FFE2	TIOR1	IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0		
H'FFE4	TIER1	TTGE	_	TCIEU	TCIEV	_	_	TGIEB	TGIEA		
H'FFE5	TSR1	TCFD	_	TCFU	TCFV	_	_	TGFB	TGFA		
H'FFE6	TCNT1										
H'FFE7	-										
H'FFE8	TGR1A										
H'FFE9	_										
H'FFEA	TGR1B										
H'FFEB	_										
H'FFF0	TCR2	_	CCLR1	CCLR0	CKEG1	CKEG0	TPSC2	TPSC1	TPSC0	TPU2	16 bit
H'FFF1	TMDR2	_	_	_	_	MD3	MD2	MD1	MD0		
H'FFF2	TIOR2	IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0		
H'FFF4	TIER2	TTGE	_	TCIEU	TCIEV	_	_	TGIEB	TGIEA		
H'FFF5	TSR2	TCFD	_	TCFU	TCFV	_	_	TGFB	TGFA		
H'FFF6	TCNT2										
H'FFF7	_										
H'FFF8	TGR2A										
H'FFF9	_	-									
H'FFFA	TGR2B										
H'FFFB	=										

- Notes: 1. Located in on-chip RAM. The bus width is 32 bits when the DTC accesses this area as register information, and 16 bits otherwise.
 - 2. Applies to the H8S/2357, H8S/2398, H8S/2396, and H8S/2395.
 - 3. If the pulse output group 2 and pulse output group 3 output triggers are the same according to the PCR setting, the NDRH address will be H'FF4C, and if different, the address of NDRH for group 2 will be H'FF4E, and that for group 3 will be H'FF4C. Similarly, if the pulse output group 0 and pulse output group 1 output triggers are the same according to the PCR setting, the NDRL address will be H'FF4D, and if different, the address of NDRL for group 0 will be H'FF4F, and that for group 1 will be H'FF4D.
 - 4. Functions as C/\overline{A} for SCI use, and as GM for smart card interface use.
 - 5. Functions as FER for SCI use, and as ERS for smart card interface use.
 - 6. Applies to the H8S/2357 ZTAT only.
 - 7. Applies to the H8S/2357F-ZTAT only.
 - 8. Applies to the H8S/2398F-ZTAT only.
 - 9. Applies to the H8S/2395F-ZTAT only.
 - 10. Applies to the H8S/2396F-ZTAT only.

B.2 Functions

MRA—DTC Mode Register A H'F800-H'FBFF DTC Bit 7 6 5 4 3 2 1 0 SM1 SM0 DM1 DM0 MD1 MD0 DTS Sz Initial value: Undefined Undefined Undefined Undefined Undefined Undefined Undefined Read/Write: DTC Data Transfer Size Byte-size transfer 1 Word-size transfer DTC Transfer Mode Select Destination side is repeat area or block area 1 Source side is repeat area or block area DTC Mode Normal mode Repeat mode 1 0 Block transfer mode **Destination Address Mode** 0 DAR is fixed 1 0 DAR is incremented after a transfer (by +1 when Sz = 0; by +2 when Sz = 1) 1 DAR is decremented after a transfer (by -1 when Sz = 0; by -2 when Sz = 1) Source Address Mode

0	_	SAR is fixed
1	0	SAR is incremented after a transfer (by +1 when Sz = 0; by +2 when Sz = 1)
	1	SAR is decremented after a transfer (by -1 when Sz = 0; by -2 when Sz = 1)

0	End of DTC data transfer
1	DTC chain transfer

SAR—DTC Source Address Register

H'F800—H'FBFF

DTC

Bit	:	23	22	21	20	19	 4	3	2	1	0
Initial value	:		Unde- fined			Unde- fined	 Unde- fined		Unde- fined		
Read/Write	:		_	_	_		 _	_	_	_	

Specifies transfer data source address

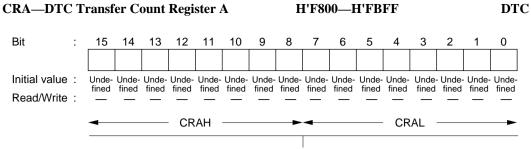
DAR—DTC Destination Address Register

H'F800—H'FBFF

DTC

Bit	:	23	22	21	20	19	 4	3	2	1	0
Initial value	:	Unde- fined			Unde- fined		 Unde- fined		Unde- fined		
Read/Write	:		_	_	_	_	 	_	_	_	

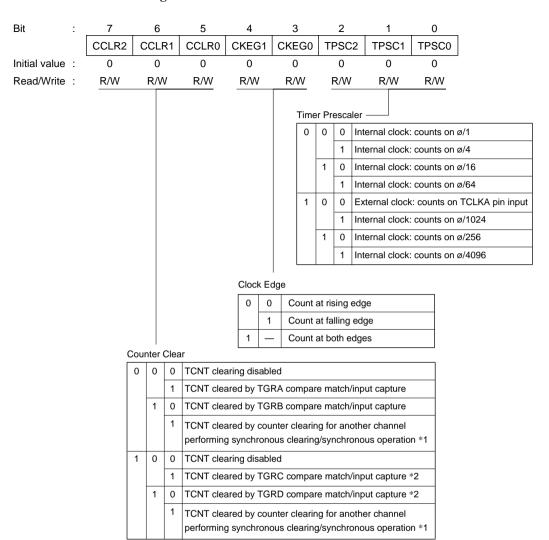
Specifies transfer data destination address



Specifies the number of DTC data transfers

CRB—DTC T	ransf	er Co	ount l	Regis	ster I	3	H'F800—H'FBFF									DTC
Bit :	_15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0_
Initial value:	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined				Unde- fined		Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined	Unde- fined
Read/Write:	_	_	_	_	_	_	_	_	_	_	_	_	_	_	_	

Specifies the number of DTC block data transfers



Notes: 1. Synchronous operation setting is performed by setting the SYNC bit in TSYR to 1.

When TGRC or TGRD is used as a buffer register, TCNT is not cleared because the buffer register setting has priority, and compare match/input capture does not occur.

Bit :	7	6	5	4	3	2		1	1	0	
	_	_	BFB	BFA	MD3	MD2		MI	D1	MD0	
Initial value:	1	1	0	0	0	0		()	0	,
Read/Write:	_	_	R/W	R/W	R/W	R/W		R/	W	R/W	
						Mod	le				
						0	0	0	0	Normal ope	ration
									1	Reserved	
								1	0	PWM mode	: 1
									1	PWM mode	2
							1	0	0	Phase cour	nting mode 1
									1	Phase cour	nting mode 2
								1	0	Phase cour	nting mode 3
									1	Phase cour	nting mode 4
						1	*	*	*	_	
										•	* : Don't care
						Notes	2.	it sho Phas set fo	ould se co or ch , 0 s	reserved bit always be w bunting mode annels 0 and hould always	ritten with 0. e cannot be d 3. In this
				Buffer	Operation A						
				0	TGRA opera	ates norn	nally				
				1	TGRA and T for buffer op		ed to	geth	ner		

Buffer Operation B

0	TGRB operates normally
1	TGRB and TGRD used together for buffer operation

Bit :	7	6	5	4		3		2	1	0	
Initial value:	IOB3	IOB2	IOB1	IOB0	IC	A3	1	OA2	IOA1	IOA0	
	0	0	0	0		0		0	0	0	
Read/Write:	R/W	R/W	R/W	R/W	R	/W		R/W	R/W	R/W	
				TOD	۰. ۱	·0 0					
				TGR	3A I	/O C	ontr	OI			
				0	0	0	0	TGR3A		disabled	
							1	is output compare	Initial o	utput is	0 output at compare match
						1	0	register	0 output		1 output at compare match
							1				Toggle output at compare match
					1	0	0		Output	disabled	
							1			utput is	0 output at compare match
						1	0		1 outpu	ıτ	1 output at compare match
							1				Toggle output at compare match
				1	0	0	0	TGR3A is input	Captur	e input	Input capture at rising edge
							1	capture	TIOCA		Input capture at falling edge
						1	*	register			Input capture at both edges
					1	*	*			e input is channel t clock	Input capture at TCNT4 count-up/count-down

* : Don't care

TGR3B I/O Control

"			•		
0	0	0	TGR3B	Output disabled	
		1	compare	Initial output is	0 output at compare match
	1	0	register	o output	1 output at compare match
		1			Toggle output at compare match
1	0	0		Output disabled	
		1		Initial output is 1	0 output at compare match
	1	0		output	1 output at compare match
		1			Toggle output at compare match
0	0	0	TGR3B	Capture input	Input capture at rising edge
		1	capture	TIOCB3 pin	Input capture at falling edge
	1	*	register		Input capture at both edges
1	*	*		Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/ count-down*1
	1 0	1 0 1	1 0 0 1 1 0 0 1 1 0 0 0 1 1 0 0 0 1	1 is output compare register	1 is output compare register Initial output is 0 output

* : Don't care

Note: 1. If bits TPSC2 to TPSC0 in TCR4 are set to B'000, and ø/1 is used as the TCNT4 count clock, this setting will be invalid and input capture will not occur.

Bit 7 6 5 4 3 2 1 0 IOD3 IOD2 IOD1 IOD0 IOC3 IOC2 IOC1 IOC0 0 Initial value : 0 0 0 0 0 0 0 R/W R/W R/W R/W R/W R/W R/W Read/Write: R/W

TRG3C I/O Control

0	0	0	0	TGR3C	Output disabled	
			1	is output compare	Initial output is 0 output	0 output at compare match
		1	0	register	Output	1 output at compare match
			1			Toggle output at compare match
	1	0	0		Output disabled	
			1		Initial output is 1	0 output at compare match
		1	0		output	1 output at compare match
			1			Toggle output at compare match
1	0	0	0	TGR3C	Capture input	Input capture at rising edge
			1	is input capture	source is TIOCC3 pin	Input capture at falling edge
		1	*	register		Input capture at both edges
	1	*	*		Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/count-down

* : Don't care

Note: When the BFA bit in TMDR3 is set to 1 and TGR3C is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

TGR3D I/O Control

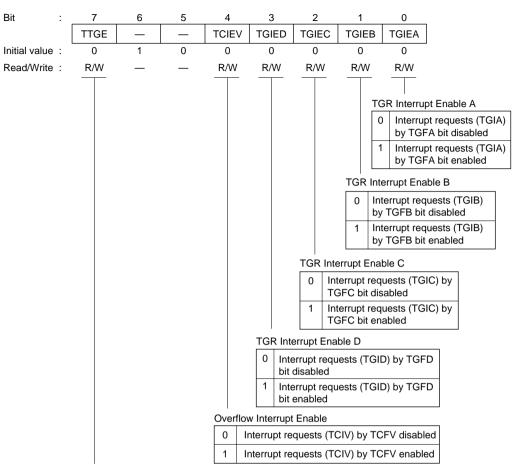
0	0	0	0	TGR3D	Output disabled						
			1	is output compare	Initial output is 0 output	0 output at compare match					
		1	0	register *2	output	1 output at compare match					
			1] _		Toggle output at compare match					
	1	0	0		Output disabled						
			1		Initial output is 1	0 output at compare match					
		1	0		output	1 output at compare match					
			1			Toggle output at compare match					
1	0	0	0	TGR3D	Capture input source is	Input capture at rising edge					
			1	is input capture	TIOCD3 pin	Input capture at falling edge					
		1	*	register *2		Input capture at both edges					
	1	*	*	_	Capture input source is channel 4/count clock	Input capture at TCNT4 count-up/ count-down*1					

* : Don't care

Notes: 1. When bits TPSC2 to TPSC0 in TCR4 are set to B'000 and ø/1 is used as the TCNT4 count clock, this setting is invalid and input capture is not

When the BFB bit in TMDR3 is set to 1 and TGR3D is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

Note: When TGRC or TGRD is designated for buffer operation, this setting is invalid and the register operates as a buffer register.



A/D Conversion Start Request Enable

	or in ordinary ordinary ordinary
0	A/D conversion start request generation disabled
1	A/D conversion start request generation enabled

Bit :	7	6	5	4	3	2	2	1	0	
	_	_	_	TCFV	TGFD	TGI	FC TO	SFB	TGFA	
Initial value :	1	1	0	0	0	0)	0	0	
Read/Write :	_	_	_	R/(W)*	R/(W)*	R/(V	N)* R/(W)*	R/(W)*	
Read/Write:				R/(W)*	Input C	Input C O I I I I I I I I I I I I I I I I I I	Capture/C [Clearing • When D DTC is • When I registe • When I while T /Output C ng condition n TCNT =	out Ca Discontinuity List on the condition of the condi	Input Capture/Output Compare Flag A O [Clearing condition] • When DTC is activated by TGIA interrupt while DISEL bit of MRB in DTC is 0 • When DMAC is activated by TGIA interrupt while DTA bit of DMADC is 1 • When 0 is written to TGFA after reading TGFA = 1 I [Setting condition] • When TCNT=TGRA while TGRA is functioning as output compare register • When TCNT value is transferred to TGRA by input capture signal while TGRA is functioning as input capture register Capture/Output Compare Flag B Clearing condition] • When DTC is 3 • When 0 is written to TGFB after reading TGFB = 1 Setting condition] • When TCNT = TGRB while TGRB is functioning as output compare register • When TCNT stativated by TGIB interrupt while DISEL bit of MRB in DTC is 0 • When TCNT is activated by TGIB is functioning as output compare register • When TCNT = TGRB while TGRB is functioning as input capture register • When TCNT value is transferred to TGRB by input capture signal while TGRB is functioning as input capture register ut Compare Flag C dition] is activated by TGIC interrupt while DISEL bit of MRB in viriten to TGFC after reading TGFC = 1	8
						TGRI	D is funct	ioning	ng as input capture register	
				Overflov	/ Flag					
					learing of them 0 is			after	or reading TCFV = 1	

Note: * Can only be written with 0 for flag clearing.

[Setting condition] When the TCNT value overflows (changes from H'FFFF to H'0000)

H'FE86

TPU3

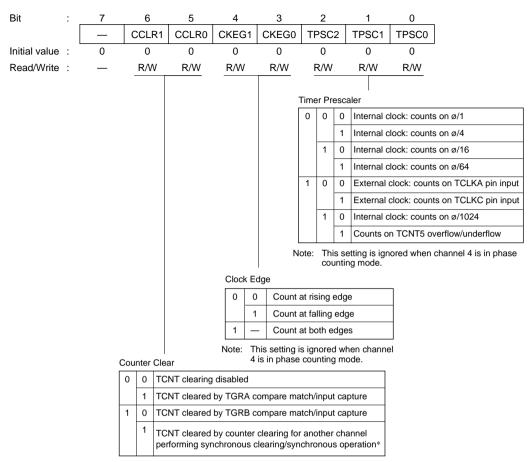
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial value	:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Up-counter

TGR3A—Timer General Register 3A	H'FE88	TPU3
TGR3B—Timer General Register 3B	H'FE8A	TPU3
TGR3C—Timer General Register 3C	H'FE8C	TPU3
TGR3D—Timer General Register 3D	H'FE8E	TPU3

Bit : 15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0

Initial value:



Note: * Synchronous operating setting is performed by setting the SYNC bit TSYR to 1.

Bit :	7	6	5	4	3	2	1	0
	_	_	_	_	MD3	MD2	MD1	MD0
Initial value :	1	1	0	0	0	0	0	0
Read/Write:	_	_	_	_	R/W	R/W	R/W	R/W
						Mada	l	
						Mode		

VI	o	d	е
٧.	•	u	•

0	0	0	0	Normal operation
			1	Reserved
		1	0	PWM mode 1
			1	PWM mode 2
	1	0	0	Phase counting mode 1
			1	Phase counting mode 2
		1	0	Phase counting mode 3
			1	Phase counting mode 4
1	*	*	*	_

* : Don't care

Notes: MD3 is a reserved bit. In a write, it should always be written with 0.

Bit :	7	6	5	4	;	3		2	1	0	
	IOB3	IOB2	IOB1	IOB0	10	A3		IOA2	IOA1	IOA0	
Initial value:	0	0	0	0	(0		0	0	0	ı
Read/Write:	R/W	R/W	R/W	R/W	R/W			R/W	R/W	R/W	
				TO	R4A	1/0 (Cor	ntrol			
				0	0	0	0	TGR4A	Output	disabled	
							1	is output compare		utput is 0	0 output at compare match
						1	0	register	output		1 output at compare match
							1				Toggle output at compare match
					1	0	0		Output	disabled	
							1			utput is 1	0 output at compare match
						1	0		output		1 output at compare match
							1				Toggle output at compare match
				1	0	0	0	TGR4A	Capture		Input capture at rising edge
							1	is input capture	source TIOCA		Input capture at falling edge
						1	*	register		·	Input capture at both edges
					1	*	*			e input is TGR3A	Input capture at generation of TGR3A compare match/input

*: Don't care

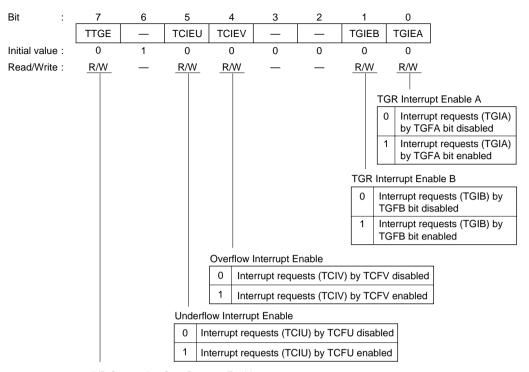
TGR4B I/O Control

	4D I/			"					
0	0	0	0	TGR4B	Output disabled				
			1	is output compare	Initial output is 0 output	0 output at compare match			
		1	0	register	σαιραί	1 output at compare match			
			1]		Toggle output at compare match			
	1	0	0		Output disabled				
			1		Initial output is 1	0 output at compare match			
		1	0		output	1 output at compare match			
			1			Toggle output at compare match			
1	0	0	0	TGR4B	Capture input	Input capture at rising edge			
			1	is input capture	source is TIOCB4 pin	Input capture at falling edge			
		1	*	register	-	Input capture at both edges			
	1	*	*		Capture input source is TGR3C compare match/ input capture	Input capture at generation of TGR3C compare match/input capture			

* : Don't care

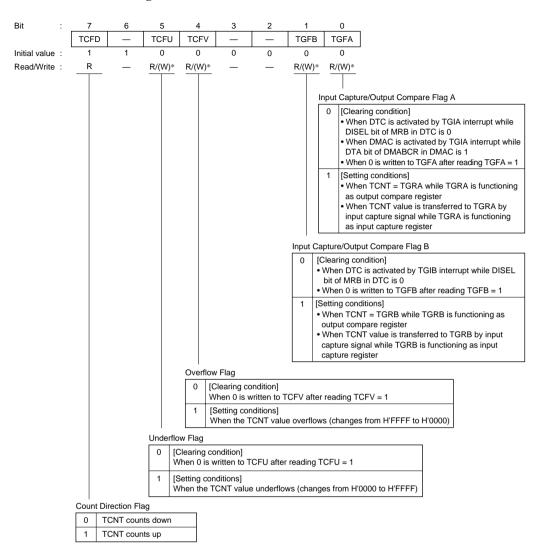
compare match/ input capture

capture



A/D Conversion Start Request Enable

0	A/D conversion start request generation disabled
1	A/D conversion start request generation enabled



Note: * Can only be written with 0 for flag clearing.

Initial value :

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial valu	e :	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Read/Write	е:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
		Up/down-counter*															

Note: * This timer counter can be used as an up/down-counter only in phase counting mode or when performing overflow/underflow counting on another channel. In other cases it functions as an up-counter.

TGR4A—	Timer	Gen	eral l	Regis	ster 4	ŀA			H				TPU4				
TGR4B—	B	H'FE9A								TPU4							
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0

Bit :	7		6	5	4		3		2		1	0	1			
	_	- 1	CCLR1	CCLR0	CKE	G1	CKEG)	TPS	C2	TPSC1	TPSC0				
Initial value:	0	·	0	0	0		0		0		0	0				
Read/Write:	_		R/W	R/W	R/\	Ν	R/W		RΛ	Ν	R/W	R/W				
								Tim	ne Pre	scal	er					
								0	0	0	Internal clo	ck: counts	on ø/1			
										1	Internal clo	ck: counts	on ø/4			
									1	0	Internal clo	ck: counts	on ø/16			
										1	Internal clo	ck: counts	on ø/64			
								1	0	0	External clo	ock: counts	on TCLKA pin input			
										1	External clock: counts on TCLKC pin input					
									1	0	Internal clo	ck: counts	on ø/256			
										1	External clo	ock: counts	on TCLKD pin input			
							N	Note			etting is ignoring mode.	red when cl	hannel 5 is in phase			
					Clock	Edae										
						0	Count at	t ric	ina o	dao						
					" -	1										
						1	Count at									
					1		Count at	DC	otn ea	ges						
											n channel					
		Cou	ا unter Cle	ar		5 IS I	n phase o	cou	ntıng	mod	ode.					
		0	0 TC	NT clearing	ı disabl	led										
				NT cleared			ompare n	nate	ch/inp	ut ca	ut capture					
		1		NT cleared							· ·					

Note: * Synchronous operating setting is performed by setting the SYNC bit TSYR to 1.

TCNT cleared by counter clearing for another channel performing synchronous clearing/synchronous operation*

Bit :	7	6	5	4	3	2	1	0
	_	_	_	_	MD3	MD2	MD1	MD0
Initial value:	1	1	0	0	0	0	0	0
Read/Write:	_	_	_	_	R/W	R/W	R/W	R/W

Mode	Э			
0	0	0	0	Normal operation
			1	Reserved
		1	0	PWM mode 1
			1	PWM mode 2
	1	0	0	Phase counting mode 1
			1	Phase counting mode 2
		1	0	Phase counting mode 3
			1	Phase counting mode 4
1	*	*	*	_

^{* :} Don't care

Notes: MD3 is a reserved bit. In a write, it should always be written with 0.

3 2 Bit 7 6 5 4 1 0 IOB3 IOB2 IOB1 IOB0 IOA3 IOA2 IOA1 IOA0 0 0 0 0 0 0 0 0 Initial value : R/W R/W R/W Read/Write: R/W R/W R/W R/W R/W

TGR5A I/O Control

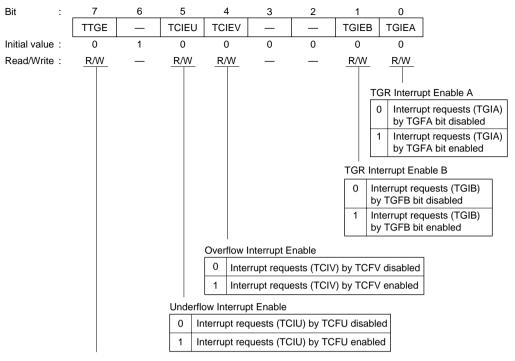
0	0	0	0	TGR5A	Output disabled	
			1	is output compare	Initial output is 0 output	0 output at compare match
		1	0	register	σαιραί	1 output at compare match
			1			Toggle output at compare match
	1	0	0		Output disabled	
			1		Initial output is 1	0 output at compare match
		1	0		output	1 output at compare match
			1			Toggle output at compare match
1	*	0	0	TGR5A	Capture input	Input capture at rising edge
			1	is input capture	source is TIOCA5 pin	Input capture at falling edge
		1	*	register		Input capture at both edges

^{* :} Don't care

TGR5B I/O Control

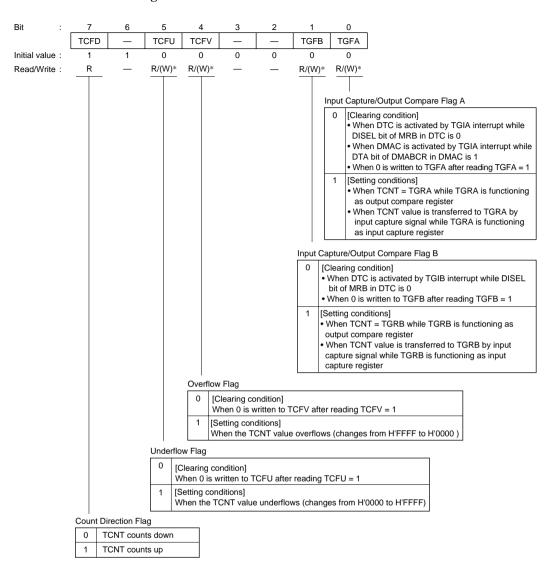
0	0	0	0	TGR5B	Output disabled				
			1	is output compare	Initial output is 0 output	0 output at compare match			
		1	0	register	σαιραί	1 output at compare match			
			1			Toggle output at compare match			
	1	0	0		Output disabled				
			1		Initial output is 1	0 output at compare match			
		1	0		output	1 output at compare match			
			1			Toggle output at compare match			
1	*	0	0	TGR5B	Capture input	Input capture at rising edge			
			1	is input capture	source is TIOCB5 pin	Input capture at falling edge			
		1	*	register		Input capture at both edges			

^{* :} Don't care



A/D Conversion Start Request Enable

0	A/D conversion start request generation disabled
1	A/D conversion start request generation enabled



Note: * Can only be written with 0 for flag clearing.

P1DDR—Port 1 Data Direction Register

Port 1

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0_
Initial value	:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
								Up/	down	-cour	nter*						

Note: * This timer counter can be used as an up/down-counter only in phase counting mode or when performing overflow/underflow counting on another channel. In other cases it functions as an up-counter.

TGR5A— TGR5B—		H'FEA8 H'FEAA									TPU5 TPU5						
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Initial va	ılue :	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1

Bit	:	7	6	5	4	3	2	1	0
		P17DDR	P16DDR	P15DDR	P14DDR	P13DDR	P12DDR	P11DDR	P10DDR
Initial value	e :	0	0	0	0	0	0	0	0
Read/Write	e :	W	W	W	W	W	W	W	W

Specify input or output for individual port 1 pins

H'FEB0

P5DDR—Port 5 Data Direction Register

Bit	:	7	6	5	4	3	2	1	0
		P27DDR	P26DDR	P25DDR	P24DDR	P23DDR	P22DDR	P21DDR	P20DDR
Initial va	lue:	0	0	0	0	0	0	0	0
Read/W	rite :	W	W	W	W	W	W	W	W

Specify input or output for individual port 2 pins

P3DDR—Port 3 Data Direction Register H'FEB2 Port 3 Bit 6 5 4 3 2 1 0 P35DDR | P34DDR | P33DDR | P31DDR | P30DDR Initial value: 0 Undefined Undefined 0 0 0 0 0 Read/Write: W W W W W W

Specify input or output for individual port 3 pins

H'FEB4

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	P53DDR	P52DDR	P51DDR	P50DDR
Initial value	:	Undefined	Undefined	Undefined	Undefined	0	0	0	0
Read/Write	:	_	_	_	_	W	W	W	W

Specify input or output for individual port 5 pins

Port 5

Bit	:	7	6	5	4	3	2	1	0
		P67DDR	P66DDR	P65DDR	P64DDR	P63DDR	P62DDR	P61DDR	P60DDR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	W	W	W	W	W	W	W	W

Specify input or output for individual port 6 pins

PADDR—Port A Data Direction Register				gister	H'FEB9			Port A		
Bit	:	7	6	5	4	3	2	1	0	
		PA7DDR	PA6DDR	PA5DDR	PA4DDR	PA3DDR	PA2DDR	PA1DDR	PA0DDR	
Initial value	:	0	0	0	0	0	0	0	0	
Read/Write	:	W	W	W	W	W	W	W	W	

Specify input or output for individual port A pins

PBDDR—Port B Data Direction Register	H'FEBA	Port B
		[On-chip ROM version Only]

Bit	:	7	6	5	4	3	2	1	0
		PB7DDR	PB6DDR	PB5DDR	PB4DDR	PB3DDR	PB2DDR	PB1DDR	PB0DDR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	W	W	W	W	W	W	W	W

Specify input or output for individual port B pins

[On-chip ROM version Only]

Bit	:	7	6	5	4	3	2	1	0
		PC7DDR	PC6DDR	PC5DDR	PC4DDR	PC3DDR	PC2DDR	PC1DDR	PC0DDR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	W	W	W	W	W	W	W	W

Specify input or output for individual port C pins

PDDDR—P	D Data Di	rection R	egister	H'FEBC F						
							[On-chip ROM version Only]			
Bit	:	7	6	5	4	3	2	1	0	
		PD7DDR	PD6DDR	PD5DDR	PD4DDR	PD3DDR	PD2DDR	PD1DDR	PD0DDR	
Initial value	:	0	0	0	0	0	0	0	0	
Read/Write	:	W	W	W	W	W	W	W	W	

Specify input or output for individual port D pins

PEDDR—Port	E Data Di	irection R	legister	Н	'FEBD	Port E			
Bit :	7	6	5	4	3	2	1	0	
	PE7DDR	PE6DDR	PE5DDR	PE4DDR	PE3DDR	PE2DDR	PE1DDR	PE0DDR	
Initial value:	0	0	0	0	0	0	0	0	
Read/Write:	W	W	W	W	W	W	W	W	

Specify input or output for individual port E pins

Bit	:	7	6	5	4	3	2	1	0
		PF7DDR	PF6DDR	PF5DDR	PF4DDR	PF3DDR	PF2DDR	PF1DDR	PF0DDR
Modes 4 to 6								'	
Initial value	:	1	0	0	0	0	0	0	0
Read/Write	:	W	W	W	W	W	W	W	W
Mode 7									
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	W	W	W	W	W	W	W	W

Specify input or output for individual port F pins

PGDDR—Por	t G	Data Di	rection Re	egister	H'FEBF				Port G		
Bit	:	7	6	5	4	3	2	1	0		
		_	_	_	PG4DDR	PG3DDR	PG2DDR	PG1DDR	PG0DDR		
Modes 4, 5			1								
Initial value	:	Undefined	Undefined	Undefined	1	0	0	0	0		
Read/Write	:	_	_	_	W	W	W	W	W		
Modes 6, 7											
Initial value	:	Undefined	Undefined	Undefined	0	0	0	0	0		
Read/Write	:	_	_	_	W	W	W	W	W		

Specify input or output for individual port G pins

IPRA — Interrupt Priority Register A	H'FEC4	Interrupt Controller
IPRB — Interrupt Priority Register B	H'FEC5	Interrupt Controller
IPRC — Interrupt Priority Register C	H'FEC6	Interrupt Controller
IPRD — Interrupt Priority Register D	H'FEC7	Interrupt Controller
IPRE — Interrupt Priority Register E	H'FEC8	Interrupt Controller
IPRF — Interrupt Priority Register F	H'FEC9	Interrupt Controller
IPRG — Interrupt Priority Register G	H'FECA	Interrupt Controller
IPRH — Interrupt Priority Register H	H'FECB	Interrupt Controller
IPRI — Interrupt Priority Register I	H'FECC	Interrupt Controller
IPRJ — Interrupt Priority Register J	H'FECD	Interrupt Controller
IPRK — Interrupt Priority Register K	H'FECE	Interrupt Controller
		•
D# -	_	

Bit :	7	6	5	4	3	2	1	0
	_	IPR6	IPR5	IPR4	_	IPR2	IPR1	IPR0
Initial value:	0	1	1	1	0	1	1	1
Read/Write:		R/W	R/W	R/W	_	R/W	R/W	R/W

Set priority (levels 7 to 0) for interrupt sources

Correspondence between Interrupt Sources and IPR Settings

Register	Bits							
rtegister	6 to 4	2 to 0						
IPRA	IRQ0	IRQ1						
IPRB	IRQ2	IRQ4						
	IRQ3	IRQ5						
IPRC	IRQ6	DTC						
	IRQ7							
IPRD	WDT	Refresh timer						
IPRE	*	A/D converter						
IPRF	TPU channel 0	TPU channel 1						
IPRG	TPU channel 2	TPU channel 3						
IPRH	TPU channel 4	TPU channel 5						
IPRI	8-bit timer channel 0	8-bit timer channel 1						
IPRJ	DMAC	SCI channel 0						
IPRK	SCI channel 1	SCI channel 2						

Note: * Reserved bits. These bits cannot be modified and are always read as 1.

Bit :	7	6	5	4	3	2	1	0
	ABW7	ABW6	ABW5	ABW4	ABW3	ABW2	ABW1	ABW0
Modes 5 to 7								
Initial value:	1	1	1	1	1	1	1	1
R/W :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Mode 4								
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Area 7 to 0 Bus Width Control

0	Area n is designated for 16-bit access
1	Area n is designated for 8-bit access

(n = 7 to 0)

Note: * Modes 6 and 7 are provided in the On-chip ROM version only.

ASTCR—Access State Control Register

H'FED1

Bus Controller

Bit :
Initial value :

Read/Write:

7	6	5	4	3	2	1	0
AST7	AST6	AST5	AST4	AST3	AST2	AST1	AST0
1	1	1	1	1	1	1	1
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Area 7 to 0 Access State Control

0	Area n is designated for 2-state access
	Wait state insertion in area n external space is disabled
1	Area n is designated for 3-state access
	Wait state insertion in area n external space is enabled

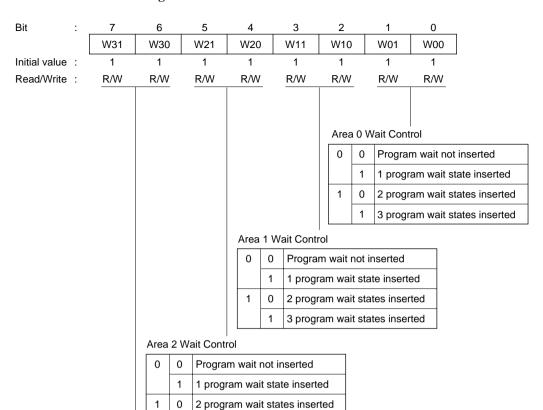
(n = 7 to 0)

Bit :	7	6	5	4		3		2		1	0	
	W71	W70	W61	W60)	W51		W50		W41	W40)
Initial value :	1	1	1	1		1		1		1	1	
Read/Write:	R/W	R/W	R/W	R/W	_	R/W		R/W		R/W	R/W	, _
								Area	4 W	ait Cont	rol	
								0	0	Prograi	m wait ı	not inserted
									1	1 progr	am wai	t state inserted
								1	0	2 progr	am wai	t states inserted
									1	3 progr	am wai	t states inserted
				Area	5 W	ait Contr	ol					
				0	0	Prograi	m	wait r	ot ir	serted		
					1	1 progr	ar	n wait	sta	te insert	ed	
				1	0	2 progr	ar	n wait	sta	tes inser	ted	
					1	3 progr	ar	n wait	sta	tes inser	ted	
		Area 6 \	Wait Conti	rol		•						
		l ———										

0	0	Program wait not inserted
	1	1 program wait state inserted
1	0	2 program wait states inserted
	1	3 program wait states inserted

Area 7 Wait Control

0	0	Program wait not inserted
	1	1 program wait state inserted
1	0	2 program wait states inserted
	1	3 program wait states inserted

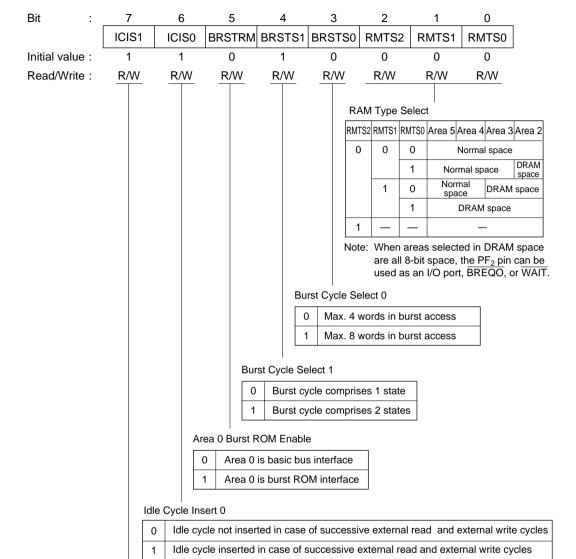


3 program wait states inserted

Area 3 Wait Control

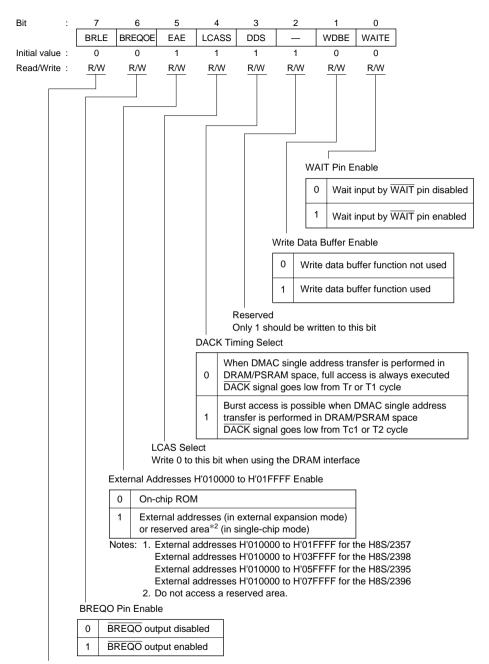
0	0	Program wait not inserted
	1	1 program wait state inserted
1	0	2 program wait states inserted
	1	3 program wait states inserted

1



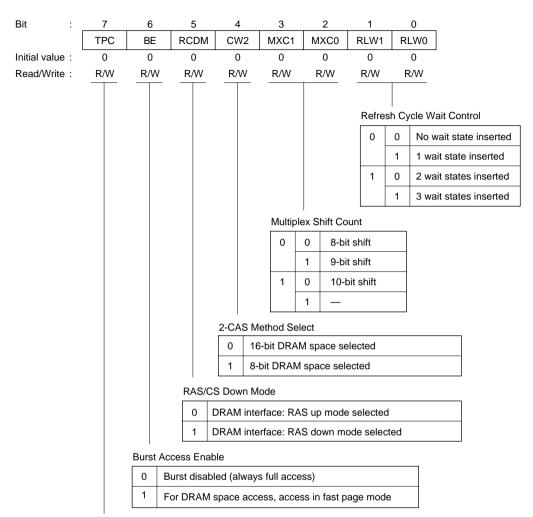
Idle Cycle Insert 1

0	Idle cycle not inserted in case of successive external read cycles in different areas
1	Idle cycle inserted in case of successive external read cycles in different areas



Bus Release Enable

0	External bus release is disabled
1	External bus release is enabled



TP Cycle Control

0	1-state precharge cycle is inserted
1	2-state precharge cycle is inserted

H'FED7

Bus Controller

Bit :	7	6	5	4	3		2		1	0	_
	RFSHE	RCW	RMODE	CMF	CMIE		CKS	2	CKS1	CKS0	
Initial value:	0	0	0	0	0		0		0	0	•
Read/Write:	R/W	R/W	R/W	R/W	R/W		R/V	/	R/W	R/W	
					F	Refre	esh C	ount	er Clock Se	elect	
						0	0	0	Count op	eration disa	bled
								1	Count use	es ø/2	
							1	0	Count use	es ø/8	
								1	Count use	es ø/32	
						1	0	0	Count use	es ø/128	
								1	Count use	es ø/512	
							1	0	Count use	es ø/2048	
								1	Count use	es ø/4096	
				Co	mpare M	atch	Inter	rupt	Enable		
					Interru	upt r	eques	st (Cl	MI) by CMF	flag disabl	ed
					Interru	upt r	eques	st (Cl	MI) by CMF	flag enable	ed
			Co	mpare Mat	ch Flag						
				Cleare	g condition d by read 0 to the 0	ling 1		MF f	lag when C	CMF = 1, the	en
			,		condition en RTCN		RTC	OR			
		Re	□								
			0 DRAM	interface: C	AS-befor	e-R/	AS ref	resh	ing used		
		- 1 ⊢		reshing use					J		
	D.	_ _									
		S-CAS Wa								_	
	0		tate insertio alls in T _{Rr} cy		efore-RA	S ref	reshi	ng di	sabled		
	1		ait state ins alls in T _{Rc1} (S-before	-RAS	S refre	eshir	ng		
	1										

Refresh Control

0	Refresh control is not performed
1	Refresh control is performed

Bit :	7	6	5	4	3	2	1	0
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

RTCNT—Refresh Timer Counter

Internal clock count value

H'FED8

Bus Controller

RTCOR—Refre	sh Time (Constant 1	Register	H	'FED9		Bus	Controlle
Bit :	7	6	5	4	3	2	1	0
Initial value:	1	1	1	1	1	1	1	1
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Sets the period for compare match operations with RTCNT

RAMER—RAM Emulation Register H'FEDB Bus Controller [for H8S/2398F-ZTAT, H8S/2396F-ZTAT and H8S/2395F-ZTAT Only]

Bit :	7	6	5	4	3	2	1	0
	_	_	_	_	RAMS	RAM2	RAM1	RAM0
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	_	_	_	_	R/W	R/W	R/W	R/W

RAM Select, Flash Memory Area Select -

To an edicot, I ladit mornery , treat edicot								
RAMS	RAM2	RAM1	RAM0	RAM Area	Block Name			
0	*	*	*	H'FFDC00 to H'FFEBFF	RAM area of 4k bytes			
1	0	0	0	H'000000 to H'000FFF	EB0 (4k bytes)			
1	0	0	1	H'001000 to H'001FFF	EB1 (4k bytes)			
1	0	1	0	H'002000 to H'002FFF	EB2 (4k bytes)			
1	0	1	1	H'003000 to H'003FFF	EB3 (4k bytes)			
1	1	0	0	H'004000 to H'004FFF	EB4 (4k bytes)			
1	1	0	1	H'005000 to H'005FFF	EB5 (4k bytes)			
1	1	1	0	H'006000 to H'006FFF	EB6 (4k bytes)			
1	1	1	1	H'007000 to H'007FFF	EB7 (4k bytes)			

^{*:} Don't care

Bit	:	7	6	5	4	3	2	1	0
		_		_	_	_	RAMS	RAM1	RAM0
Initial value :		0	0	0	0	0	0	0	0
Read/Write:		_	_	_	_	_	R/W	R/W	R/W

RAM Select, Flash Memory Area

0	o.oot,	ao	mory mou
RAMS	RAM1	RAM0	Area
0	*	*	H'FFDC00 to H'FFDFFF
1	0	0	H'000000 to H'0003FF
		1	H'000400 to H'0007FF
	1	0	H'000800 to H'000BFF
		1	H'000C00 to H'000FFF

^{*:} Don't care

H'FEE0 H'FEE2 DMAC DMAC

Bit	:	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
MAR0AH	:		_	_	_	_	_	_	_								
Initial value	:	0	0	0	0	0	0	0	0	*	*	*	*	*	*	*	*
Read/Write	:	_	_	_	_	_	_	_	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
D:t		4.5	4.4	40	40	4.4	40	0	0	7	•	_	4	2	0	4	0
Bit	:	_15_	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
MAR0AL	:																
Initial value	:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*

*: Undefined

In short address mode: Specifies transfer source/transfer destination address In full address mode: Specifies transfer source address

H'FEE4

DMAC

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	_
IOAR0A	:																	
Initial value	e :	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	•

*: Undefined

In short address mode: Specifies transfer source/transfer destination address In full address mode: Not used

Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
ETCR0A :																
Initial value:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	/ R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Sequential mode Idle mode Normal mode							Trar	sfer	coun	ter						
Repeat mode	Tra	ansfe	r num	nber	storaç	ge re	gister		_		Tı	ransf	er co	unter		
Block transfer mode		Bloc	k size	stor	age r	egist	er		_		Bl	ock s	ize c	ounte	r	
														*:	Unde	efined
MAR0BH—Mo	emor	y Ad	dress	Reg	gister	0BH	I	F	I'FEI	E8]	DMA(
MAR0BL—Me		-		_	-			I	I'FE	EA]	DMA(
Bit :	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
MAR0BH :			_		_	_	_	_								
Initial value:	0	0	0	0	0	0	0	0	*	*	*	*	*	*	*	*
Read/Write:	_	_	_	_	_	_	_	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
MAR0BL :																
Initial value :	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*

In short address mode: Specifies transfer source/transfer destination address In full address mode: Specifies transfer destination address

*: Undefined

*: Undefined

Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
IOAR0B :																
Initial value:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
														*:	Unde	fined
	In sh	ort a	ddres	ss mo	ode: S	Speci	fies tı	ansf	er so	urce/t	ransf	er de	estina	tion a	addre	SS
	In fu	ll add	lress	mode	e: No	t use	d									
ETCR0B—Tra	nsfer Count Register 0B H'FEEE DMAC															DMAC
Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
ETCR0B :																
Initial value:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Commential																
Sequential mode and idle mode							Т	ransf	er co	unte	•					
Repeat mode									_							
	Tra	nsfer	num	ber s	torag	ge reg	jister					Tran	sfer o	count	er	
Block transfer									,							
mode						E	Block	trans	ter c	ounte	r					

MAR1AH—N		-		-	-		H'FEF0 H'FEF2						DMA DMA				
MAR1AL—N	v1e	mor	y Ad	dress	s Keg	ŀ	1'FE	FZ					j	DMA			
Bit	:	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
MAR1AH	:		_		_	_	_	_									
Initial value	: '	0	0	0	0	0	0	0	0	*	*	*	*	*	*	*	*
Read/Write	:	_	_	_	_	_		_	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
MAR1AL	: [

*: Undefined

In short address mode: Specifies transfer source/transfer destination address In full address mode: Specifies transfer source address

IOAR1A—I/O	Addı	ess I	Regis	ter 1	A			Н	['FE]	F 4]	DMAC
Bit :	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
IOAR1A :																
Initial value:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
														*:	Unde	fined
	In sh	ort a	ddres	s mo	de: S	Specif	ies tr	ansfe	er soi	irce/t	ransf	er de	stina	tion a	ddre	SS

In short address mode: Specifies transfer source/transfer destination address In full address mode: Not used

E	3it	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	ETCR1A	:																
I	nitial value	: '	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
F	Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/V	ν R/\	W R/W	V R/W	R/W
Sequential r Idle mode Normal mod		-							T	ransf	er co	unter						
Repeat mod	de	-	Tr	ansfe	er nur	mber	stora	ge re	giste	 r			Tı	rans	fer c	ounte	r	
Block transf	er mode	-		Blo	ck siz	ze sto	rage	regis	ter				Ble	ock	size	count	er	
																*:	Unde	fined
MAR1BH – MAR1BL –		•			_	•			_	I'FE I'FE								DMA(
Bit	: 31	30) 2	9 2	28	27	26	25	24	23	22	21	1 2	20	19	18	17	16
MAR1BH	:		- -	- -	_	_	_	_	_									
Initial value	e: 0	0	()	0	0	0	0	0	*	*	*		*	*	*	*	*
Read/Write	e: —	_	_		_	_	_	_	_	R/V	/ R/V	۷R/۱	N R	/W	R/W	R/W	R/W	R/W
Bit	: 15	14	1:	3 1	2	11	10	9	8	7	6	5		4	3	2	1	0
MAR1BL	:																	
Initial value	e: *	*	*		*	*	*	*	*	*	*	*		*	*	*	*	
																		*
Read/Write	e: R/W	R/V	V R/	W R	/W F	R/W F	R/W	R/W	R/W	R/V	/ R/V	۷R/۱	N R	/W	R/W	R/W	R/W	

In short address mode: Specifies transfer source/transfer destination address In full address mode: Specifies transfer destination address

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
IOAR1B	:																
Initial value	:	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

*: Undefined

In short address mode: Specifies transfer source/transfer destination address In full address mode: Not used

ETCR1B—Transfer	Count	Register	1B
-----------------	-------	----------	----

H'FEFE

DMAC

							-	-	-	-	-	-	-		-	-
ETCR1B :																
Initial value :	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*	*
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Sequential mode																
and idle mode							Т	ransf	er co	unter						

Repeat mode Transfer number storage register

Transfer counter

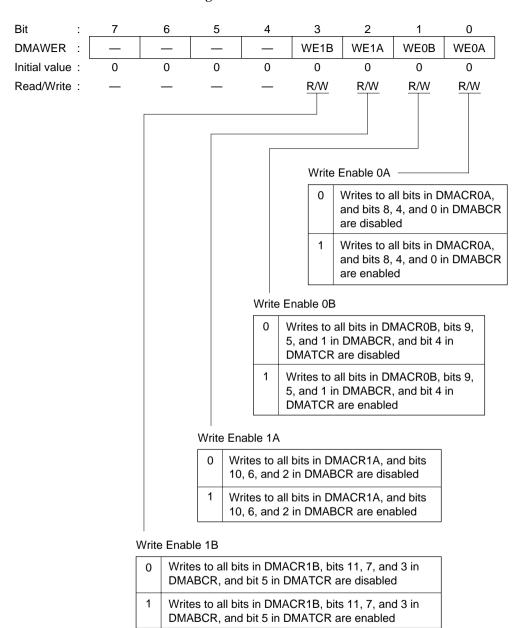
Block transfer mode

Bit

Block transfer counter

*: Undefined

Note: Not used in normal mode.



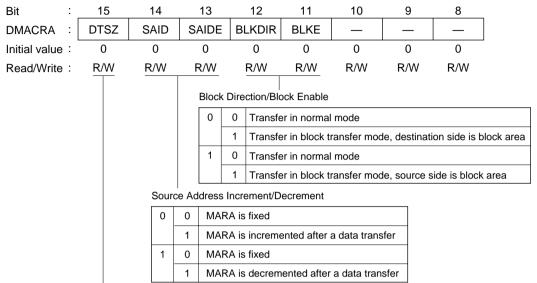
Bit :	7	6	5	4	3	2	1	0
DMATCR :	_	_	TEE1	TEE0	_	_	_	_
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	_	_	R/W	R/W Transf	— er End Ena	— able 0	_	_
				0 T	END0 pin	output dis	abled	
				1 T	END0 pin	output ena	abled	

Transfer End Enable 1

0	TEND1 pin output disabled
1	TEND1 pin output enabled

DMACR0A—DMA Control Register 0A	H'FF02	DMAC
DMACR0B—DMA Control Register 0B	H'FF03	DMAC
DMACR1A—DMA Control Register 1A	H'FF04	DMAC
DMACR1B—DMA Control Register 1B	H'FF05	DMAC

Full address mode



Data Transfer Size

0	Byte-size transfer
1	Word-size transfer

Full address mode (cont)

F1 DTF0
0
W R/W
)

Data Transfer Factor

DTF 3	DTF 2	DTF 1	DTF 0	Block Transfer Mode	Normal Mode
0	0	0	0	_	_
			1	Activated by A/D converter conversion end interrupt	_
		1	0	Activated by DREQ pin falling edge input	Activated by DREQ pin falling edge input
			1	Activated by DREQ pin low-level input	Activated by DREQ pin low-level input
	1	0	0	Activated by SCI channel 0 transmission data empty interrupt	_
			1	Activated by SCI channel 0 reception data full interrupt	_
		1	0	Activated by SCI channel 1 transmission data empty interrupt	Auto-request (cycle steal)
			1	Activated by SCI channel 1 reception data full interrupt	Auto-request (burst)
1	0	0	0	Activated by TPU channel 0 compare match/input capture A interrupt	_
			1	Activated by TPU channel 1 compare match/input capture A interrupt	_
		1	0	Activated by TPU channel 2 compare match/input capture A interrupt	_
			1	Activated by TPU channel 3 compare match/input capture A interrupt	_
	1	0	0	Activated by TPU channel 4 compare match/input capture A interrupt	_
			1	Activated by TPU channel 5 compare match/input capture A interrupt	_
		1	0	_	_
			1	_	_

Destination Address Increment/Decrement

0	0	MARB is fixed
	1	MARB is incremented after a data transfer
1	0	MARB is fixed
	1	MARB is decremented after a data transfer

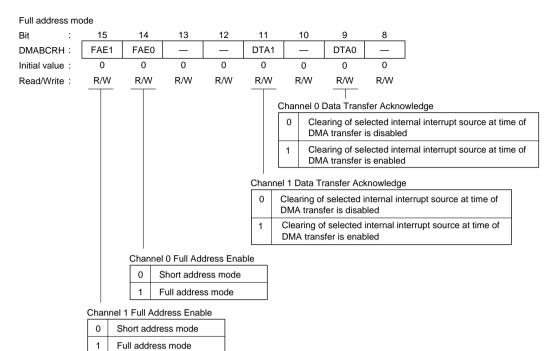
Short address mode 2 Bit 7 6 5 4 3 0 1 RPE DTF3 **DMACR** DTSZ DTID **DTDIR** DTF2 DTF1 DTF₀ 0 0 0 0 0 Initial value: 0 0 0 Read/Write: R/W R/W R/W R/W R/W R/W R/W R/W Data Transfer Factor Channel A Channel B 0 0 0 0 Data Transfer Direction Activated by A/D converter conversion Dual address mode: Transfer with 1 end interrupt MAR as source address and IOAR as destination address Activated by DREQ pin 0 Single address mode: Transfer with falling edge input MAR as source address and DACK pin as write strobe Activated by DREQ pin 1 low-level input Dual address mode: Transfer with IOAR as source address and MAR 1 0 0 Activated by SCI channel 0 transmission as destination address data empty interrupt Single address mode: Transfer with DACK pin as read strobe and MAR Activated by SCI channel 0 reception as destination address data full interrupt Activated by SCI channel 1 transmission 0 1 Repeat Enable data empty interrupt Transfer in sequential mode Activated by SCI channel 1 reception data full interrupt Transfer in repeat mode or idle mode 1 1 0 0 Activated by TPU channel 0 compare Data Transfer Increment/Decrement match/input capture A interrupt MAR is incremented after a data transfer Activated by TPU channel 1 compare match/input capture A interrupt MAR is decremented after a data transfer 1 Data Transfer Size Activated by TPU channel 2 compare match/input capture A interrupt Byte-size transfer Activated by TPU channel 3 compare 1 Word-size transfer match/input capture A interrupt 0 1 Activated by TPU channel 4 compare

match/input capture A interrupt

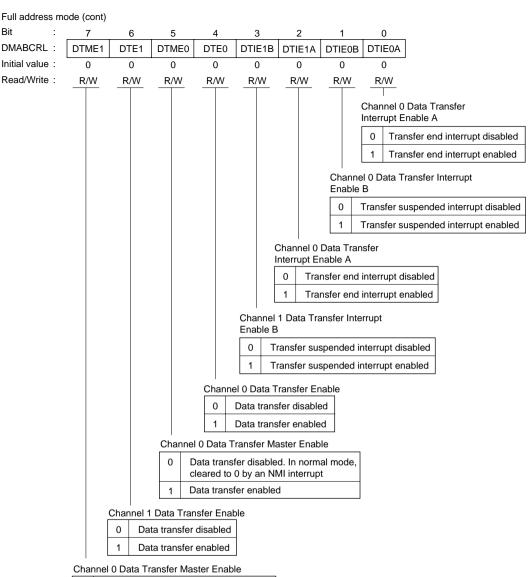
Activated by TPU channel 5 compare match/input capture A interrupt

0

H'FF06 H'FF07 DMAC DMAC



(Continued on next page)



0	Data transfer disabled. In normal mode, cleared to 0 by an NMI interrupt
1	Data transfer enabled

(Continued on next page)

Short address mode 13 12 9 Bit 15 14 11 10 8 FAE0 DTA1B DTA1A DMABCRH: FAE1 SAE1 SAE0 DTA0B DTA0A Initial value : 0 0 0 0 0 0 0 0 Read/Write · R/W R/W R/W R/W R/W R/W R/W R/W Channel 0A Data Transfer Acknowledge Clearing of selected internal interrupt source at time of DMA transfer is disabled Clearing of selected internal interrupt source at time of DMA transfer is enabled Channel 0B Data Transfer Acknowledge Clearing of selected internal interrupt source at time of DMA transfer is disabled Clearing of selected internal interrupt source at time of DMA transfer is enabled Channel 1A Data Transfer Acknowledge Clearing of selected internal interrupt source at time of DMA transfer is disabled 1 Clearing of selected internal interrupt source at time of DMA transfer is enabled Channel 1B Data Transfer Acknowledge Clearing of selected internal interrupt source at time of DMA transfer is disabled Clearing of selected internal interrupt 1 source at time of DMA transfer is enabled Channel 0B Single Address Enable Transfer in dual address mode Transfer in single address mode Channel 1B Single Address Enable Transfer in dual address mode 1 Transfer in single address mode Channel 0 Full Address Enable Short address mode 1 Full address mode

Channel 1 Full Address Enable

0	Short address mode						
1	Full address mode						

(Continued on next page)

Short address mode (cont) 6 5 4 3 2 0 Bit 7 1 DMABCRL: DTE1B DTE1A DTE0B DTE0A DTIE1B DTIE1A DTIE0B DTIE0A 0 0 Initial value: 0 0 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W R/W R/W R/W Channel 0A Data Transfer Interrupt Enable Transfer end interrupt disabled Transfer end interrupt enabled Channel 0B Data Transfer Interrupt Enable 0 Transfer end interrupt disabled Transfer end interrupt enabled Channel 1A Data Transfer Interrupt Enable Transfer end interrupt disabled Transfer end interrupt enabled Channel 1B Data Transfer Interrupt Enable 0 Transfer end interrupt disabled Transfer end interrupt enabled Channel 0A Data Transfer Enable 0 Data transfer disabled Data transfer enabled Channel 0B Data Transfer Enable

Channel 1A Data Transfer Enable

Data transfer disabled

Data transfer enabled

0	Data transfer disabled
1	Data transfer enabled

Channel 1B Data Transfer Enable

0	Data transfer disabled
1	Data transfer enabled

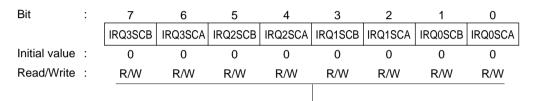
ISCRH — IRQ Sense Control Register H	H'FF2C	Interrupt Controller
ISCRL — IRQ Sense Control Register L	H'FF2D	Interrupt Controller

ISCRH

Bit	:	15	14	13	12	11	10	9	8
		IRQ7SCB	IRQ7SCA	IRQ6SCB	IRQ6SCA	IRQ5SCB	IRQ5SCA	IRQ4SCB	IRQ4SCA
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

IRQ7 to IRQ4 Sense Control

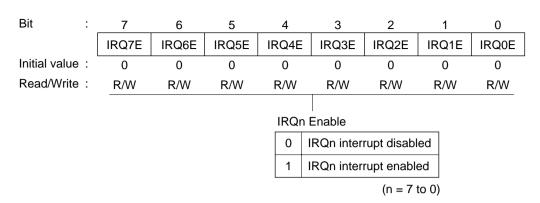
ISCRL



IRQ3 to IRQ0 Sense Control

IRQnSCB	IRQnSCA	Interrupt Request Generation
0	0	IRQn input low level
	1	Falling edge of IRQn input
1	0	Rising edge of IRQn input
	1	Both falling and rising edges of IRQn input

(n = 7 to 0)



ISR—IRQ Status Register

H'FF2F

Interrupt Controller

Bit	:	7	6	5	4	3	2	1	0
		IRQ7F	IRQ6F	IRQ5F	IRQ4F	IRQ3F	IRQ2F	IRQ1F	IRQ0F
Initial value	e: .	0	0	0	0	0	0	0	0
Read/Write	e :	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*

Indicate the status of IRQ7 to IRQ0 interrupt requests

Note: * Can only be written with 0 for flag clearing.

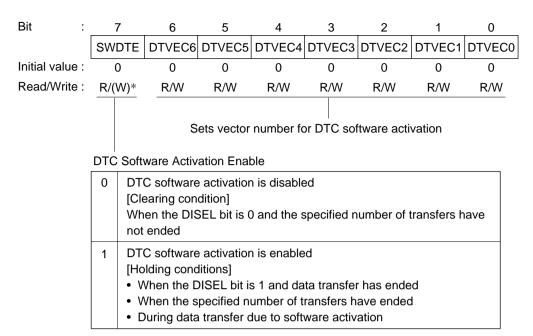
Bit	:	7	6	5	4	3	2	1	0
		DTCE7	DTCE6	DTCE5	DTCE4	DTCE3	DTCE2	DTCE1	DTCE0
Initial val	ue:	0	0	0	0	0	0	0	0
Read/Wr	ite:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

DTC Activation Enable

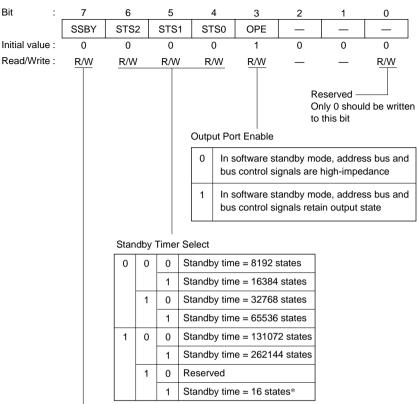
0	DTC activation by this interrupt is disabled [Clearing conditions] • When the DISEL bit is 1 and data transfer has ended •When the specified number of transfers have ended
1	DTC activation by this interrupt is enabled [Holding condition] When the DISEL bit is 0 and the specified number of transfers have not ended

Correspondence between Interrupt Sources and DTCER

Register	7	6	5	4	3	2	1	0
DTCERA	IRQ0	IRQ1	IRQ2	IRQ3	IRQ4	IRQ5	IRQ6	IRQ7
DTCERB	_	ADI	TGI0A	TGI0B	TGI0C	TGI0D	TGI1A	TGI1B
DTCERC	TGI2A	TGI2B	TGI3A	TGI3B	TGI3C	TGI3D	TGI4A	TGI4B
DTCERD	_	_	TGI5A	TGI5B	CMIA0	CMIB0	CMIA1	CMIB1
DTCERE	DMTEND0A	DMTEND0B	DMTEND1A	DMTEND1B	RXI0	TXI0	RXI1	TXI1
DTCERF	RXI2	TXI2	_	_	_	_	_	_



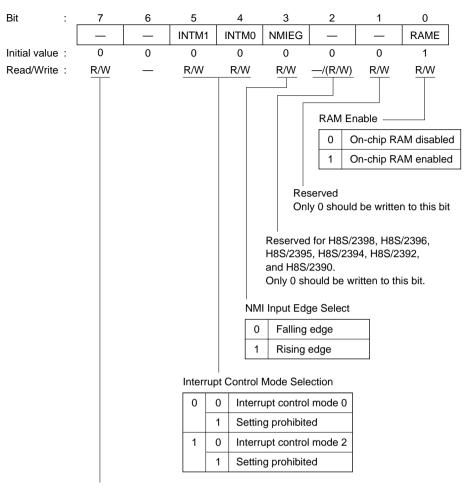
Note: * A value of 1 can always be written to the SWDTE bit, but 0 can only be written after 1 is read.



Note: * Not available in the F-ZTAT version.

Software Standby

	0	Transition to sleep mode after execution of SLEEP instruction
ſ	1	Transition to software standby mode after execution of SLEEP instruction

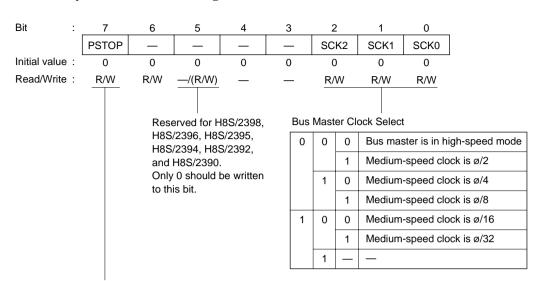


Reserved
Only 0 should be written to this bit

SCKCR—System Clock Control Register

H'FF3A

Clock Pulse Generator



ø Clock Output Control

PSTOP	Normal Operation	Sleep Mode	Software Standby Mode	Hardware Standby Mode
0	ø output	ø output	Fixed high	High impedance
1	Fixed high	Fixed high	Fixed high	High impedance

MCU

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	_	MDS2	MDS1	MDS0
Initial value	е:	1	0	0	0	0	*	*	*
Read/Write	e :	_	_	_	_	_	R	R	R

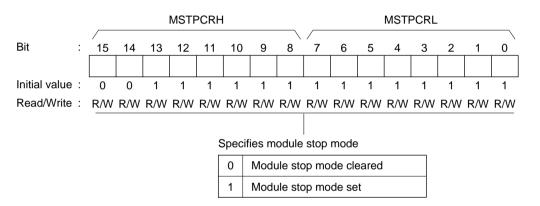
Current mode pin operating mode

Note: * Determined by pins MD₂ to MD₀

MSTPCRH — Module Stop Control Register H H'FF3C MSTPCRL — Module Stop Control Register L H'FF3D

Power-Down State Power-Down State

MCU



SYSCR2—System Control Register 2 H'FF42 [F-ZTAT Only] 3 Bit 2 0 5 FLSHE Initial value: 0 0 0 0 Read/Write: R/W

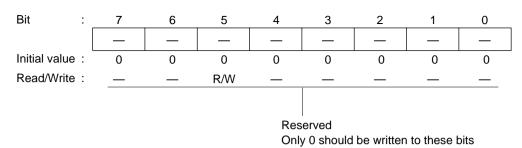
Flash memory control register enable

Flash memory control register is not selected Flash memory control register is selected

Note: SYSCR2 can only be accessed in the F-ZTAT version. In other versions, this register cannot be written to and will return an undefined value if read.

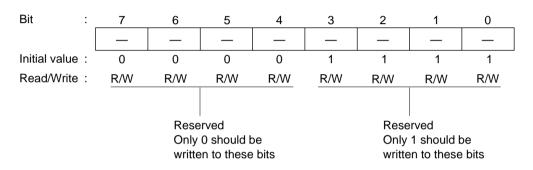
Reserved Register

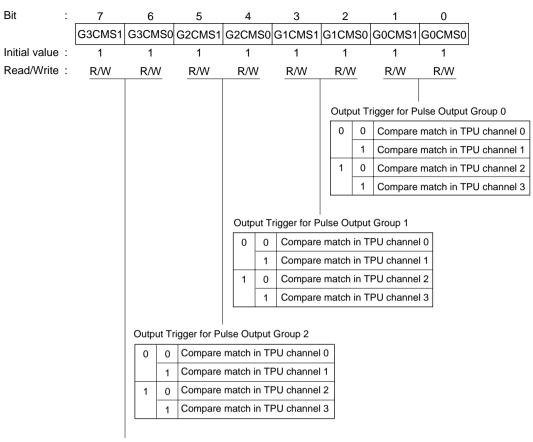
H'FF44



Reserved Register

H'FF45





Output Trigger for Pulse Output Group 3

0	0	Compare match in TPU channel 0
	1	Compare match in TPU channel 1
1	0	Compare match in TPU channel 2
	1	Compare match in TPU channel 3

Bit :	7	6	5	4	3	2	1	0				
	G3INV	G2INV	G1INV	G0INV	G3NOV	G2NOV	G1NOV	G0NOV				
Initial value:	1	1	1	1	0	0	0	0				
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W				
			Pulse Output Group n Normal/Non-Overlap Operation Select									
			Normal operation in pulse output group n (output values updated at compare match A in the selected TPU channel)									
				,								
								n=3 to 0				

Pulse Output Group n Direct/Inverted Output

0	Inverted output for pulse output group n (low-level output at pin for a 1 in PODRH)
1	Direct output for pulse output group n (high-level output at pin for a 1 in PODRH)

n=3 to 0

NDERH

7	6	5	4	3	2	1	0
NDER15	NDER14	NDER13	NDER12	NDER11	NDER10	NDER9	NDER8
0	0	0	0	0	0	0	0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	0	0 0	0 0 0	0 0 0 0	0 0 0 0 0	0 0 0 0 0	7 6 5 4 3 2 1 NDER15 NDER14 NDER13 NDER12 NDER11 NDER10 NDER9 0 0 0 0 0 0 0 R/W R/W R/W R/W R/W R/W R/W

Pulse Output Enable/Disable

0	Pulse outputs PO15 to PO8 are disabled
1	Pulse outputs PO15 to PO8 are enabled

NDERL

Bit	:	7	6	5	4	3	2	1	0
		NDER7	NDER6	NDER5	NDER4	NDER3	NDER2	NDER1	NDER0
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Pulse Output Enable/Disable

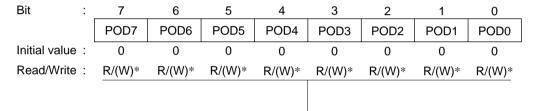
0	Pulse outputs PO7 to PO0 are disabled
1	Pulse outputs PO7 to PO0 are enabled

PODRH

Bit :	7	6	5	4	3	2	1	0
	POD15	POD14	POD13	POD12	POD11	POD10	POD9	POD8
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*

Stores output data for use in pulse output

PODRL



Stores output data for use in pulse output

Note: * A bit that has been set for pulse output by NDER is read-only.

(1) When pulse output group output triggers are the same

(a) Address: H'FF4C

Bit 7 6 5 4 3 2 1 0 NDR15 NDR14 NDR13 NDR12 NDR11 NDR₁₀ NDR9 NDR8 Initial value: 0 0 0 0 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W R/W R/W R/W

Stores the next data for pulse output groups 3 and 2

(b) Address: H'FF4E

 Bit
 :
 7
 6
 5
 4
 3
 2
 1
 0

 —
 —
 —
 —
 —
 —
 —
 —

 Initial value :
 1
 1
 1
 1
 1
 1
 1
 1

 Read/Write :
 —
 —
 —
 —
 —
 —
 —

(2) When pulse output group output triggers are different

(a) Address: H'FF4C

Bit 7 6 5 4 3 0 NDR15 NDR14 NDR13 NDR12 Initial value: 0 0 0 0 1 Read/Write: R/W R/W R/W R/W

Stores the next data for pulse output group 3

(b) Address: H'FF4E

Bit 3 2 5 4 1 0 NDR11 NDR₁₀ NDR9 NDR8 Initial value: 1 0 0 0 0 Read/Write: R/W R/W R/W R/W

Stores the next data for pulse output group 2

- (1) When pulse output group output triggers are the same
 - (a) Address: H'FF4D

Bit	: _	7	6	5	4	3	2	1	0
		NDR7	NDR6	NDR5	NDR4	NDR3	NDR2	NDR1	NDR0
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores the next data for pulse output groups 1 and 0

(b) Address: H'FF4F

Bit	:	7	6	5	4	3	2	1	0
		_	_	_	_	_	_	_	_
Initial value	:	1	1	1	1	1	1	1	1
Read/Write	:	_	_	_	_	_	_	_	_

- (2) When pulse output group output triggers are different
 - (a) Address: H'FF4D

Bit 7 6 5 4 NDR7 NDR6 NDR5 NDR4 Initial value: 0 0 0 0 Read/Write: R/W R/W R/W R/W

Stores the next data for pulse output group 1

(b) Address: H'FF4F

Bit	:	7	6	5	4	3	2	1	0	
		_	_	_	_	NDR3	NDR2	NDR1	NDR0	
Initial value	e :	1	1	1	1	0	0	0	0	
Read/Write	e :	_	_	_	_	R/W	R/W	R/W	R/W	

Stores the next data for pulse output group 0

P17 P16 P15 P13 P12 P11 P10 P14 ___* Initial value: ___* ___* ___* ___* ___* Read/Write: R R R R R R R R

State of port 1 pins

Note: * Determined by the state of pins P1₇ to P1₀.

PORT2—Port 2 Register

H'FF51

Port 2

Bit 2 7 6 5 4 3 1 0 P27 P26 P25 P24 P23 P22 P21 P20 Initial value: __* ___* ___* ___* ___* __* ___* ___* Read/Write: R R R R R R R R

State of port 2 pins

Note: * Determined by the state of pins P2₇ to P2₀.

PORT3—Port 3 Register

H'FF52

Port 3

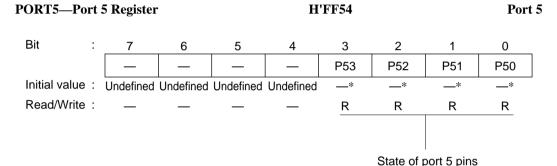
Bit 5 2 7 6 4 3 1 0 P35 P34 P33 P32 P30 P31 __* __* __* __* Initial value: Undefined Undefined __* __* Read/Write: R R R R R R

State of port 3 pins

Note: * Determined by the state of pins P3₅ to P3₀.

Bit 6 5 2 1 7 3 0 P47 P46 P42 P45 P44 P43 P41 P40 ___* ___* Initial value: ___* ___* ___* ___* ___* ___* Read/Write: R R R R R R R R State of port 4 pins

Note: * Determined by the state of pins P4₇ to P4₀.



Note: * Determined by the state of pins P5₃ to P5₀.

PORT6—Port 6 Register

H'FF55

Port 6

Bit 7 6 5 4 3 2 1 0 P67 P66 P65 P64 P63 P62 P61 P60 __* __* Initial value: ___* ___* ___* ___* ___* ___* Read/Write: R R R R R R R R

State of port 6 pins

Note: * Determined by the state of pins P67 to P60.

Bit 7 6 5 4 3 2 1 0 PA7 PA6 PA₅ PA4 PA3 PA2 PA1 PA0 Initial value: ___* ___* ___* ___* ___* ___* ___* ___* Read/Write: R R R R R R R R

State of port A pins

Note: * Determined by the state of pins PA₇ to PA₀.

PORTB—Port B Register

H'FF5A

Port B

[On-chip ROM version Only]

Bit :	7	6	5	4	3	2	1	0
	PB7	PB6	PB5	PB4	PB3	PB2	PB1	PB0
Initial value:	*	*	*	*	*	*	*	*
Read/Write:	R	R	R	R	R	R	R	R

State of port B pins

Note: * Determined by the state of pins PB₇ to PB₀.

PORTC—Port C Register

H'FF5B

Port C

[On-chip ROM version Only)]

Bit 2 7 6 5 4 3 1 0 PC7 PC6 PC5 PC4 PC3 PC2 PC1 PC0 Initial value: ___* ___* Read/Write: R R R R R R R R

State of port C pins

Note: * Determined by the state of pins PC₇ to PC₀.

Port D
[On-chip ROM version Only]

Bit 7 3 2 6 5 4 1 0 PD7 PD5 PD3 PD2 PD1 PD0 PD6 PD4 Initial value: __* __* ___* __* ___* ___* __* ___* Read/Write: R R R R R R R R

State of port D pins

Note: * Determined by the state of pins PD₇ to PD₀.

PORTE—Port E Register

H'FF5D

Port E

Bit 2 7 6 5 4 3 1 0 PE4 PE7 PE6 PE5 PE3 PE2 PE1 PE0 __* __* __* Initial value: __* ___* __* ___* __* Read/Write: R R R R R R R R

State of port E pins

Note: * Determined by the state of pins PE₇ to PE₀.

PORTF—Port F Register

H'FF5E

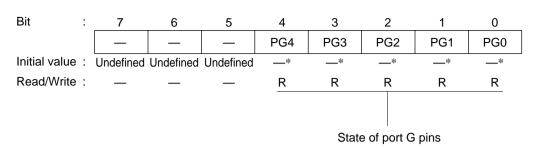
Port F

Bit 7 6 5 4 3 2 0 1 PF1 PF7 PF6 PF5 PF4 PF3 PF2 PF0 Initial value: __* ___* __* ___* __* __* __* __* Read/Write: R R R R R R R R

State of port F pins

Note: * Determined by the state of pins PF₇ to PF₀.

Port G



Note: * Determined by the state of pins PG₄ to PG₀.

P1DR—Port 1 Data Register

H'FF60

Port 1

Bit 7 6 5 4 3 2 1 0 P15DR P17DR P16DR P13DR P12DR P11DR P10DR P14DR Initial value: 0 0 0 0 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W R/W R/W R/W

Stores output data for port 1 pins (P1₇ to P1₀)

P2DR—Port 2 Data Register

H'FF61

Port 2

Bit	:	7	6	5	4	3	2	1	0
		P27DR	P26DR	P25DR	P24DR	P23DR	P22DR	P21DR	P20DR
Initial valu	e :	0	0	0	0	0	0	0	0
Read/Writ	e :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port 2 pins (P2₇ to P2₀)

Bit	:	7	6	5	4	3	2	1	0
		_	_	P35DR	P34DR	P33DR	P32DR	P31DR	P30DR
Initial val	ue :	Undefined	Undefined	0	0	0	0	0	0
Read/Wr	ite:	_	_	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port 3 pins ($P3_5$ to $P3_0$)

P5DR—Port 5 Data Register

H'FF64

Port 5

Bit :	7	6	5	4	3	2	1	0
	_	_	_	_	P53DR	P52DR	P51DR	P50DR
Initial value:	Undefined	Undefined	Undefined	Undefined	0	0	0	0
Read/Write:	_	_	_	_	R/W	R/W	R/W	R/W

Stores output data for port 5 pins (P5₃ to P5₀)

P6DR—Port 6 Data Register

H'FF65

Port 6

Bit :	7	6	5	4	3	2	1	0
	P67DR	P66DR	P65DR	P64DR	P63DR	P62DR	P61DR	P60DR
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port 6 pins (P6₇ to P6₀)

2 1 0 Bit 7 6 5 4 3 PA7DR PA6DR PA5DR PA4DR PA3DR PA2DR PA1DR PA0DR Initial value: 0 0 0 0 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W R/W R/W R/W

Stores output data for port A pins (PA₇ to PA₀)

PBDR—Port B Data Register

H'FF6A

Port B

Bit :	7	6	5	4	3	2	1	0
	PB7DR	PB6DR	PB5DR	PB4DR	PB3DR	PB2DR	PB1DR	PB0DR
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port B pins (PB₇ to PB₀)

PCDR—Port C Data Register

H'FF6B

Port C

Bit	:	7	6	5	4	3	2	1	0
		PC7DR	PC6DR	PC5DR	PC4DR	PC3DR	PC2DR	PC1DR	PC0DR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port C pins (PC₇ to PC₀)

Bit :	7	6	5	4	3	2	1	0
	PD7DR	PD6DR	PD5DR	PD4DR	PD3DR	PD2DR	PD1DR	PD0DR
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port D pins (PD₇ to PD₀)

PEDR—Port E Data Register

H'FF6D

Port E

Bit :	7	6	5	4	3	2	1	0
	PE7DR	PE6DR	PE5DR	PE4DR	PE3DR	PE2DR	PE1DR	PE0DR
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port E pins (PE₇ to PE₀)

PFDR—Port F Data Register

H'FF6E

Port F

Bit	: .	7	6	5	4	3	2	1	0
		PF7DR	PF6DR	PF5DR	PF4DR	PF3DR	PF2DR	PF1DR	PF0DR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores output data for port F pins (PF₇ to PF₀)

Bit 4 3 2 1 0 5 PG4DR PG3DR PG2DR PG1DR PG0DR Initial value: Undefined Undefined Undefined 0 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W

Stores output data for port G pins (PG₄ to PG₀)

PAPCR—Port A MOS Pull-Up Control Register H'FF70

Port A
[On-chip ROM version Only]

Bit 7 6 5 4 3 2 1 0 PA7PCR PA6PCR PA5PCR PA4PCR PA3PCR PA2PCR PA1PCR PA0PCR Initial value: 0 0 0 0 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W R/W R/W R/W

Controls the MOS input pull-up function incorporated into port A on a bit-by-bit basis

Note: Setting is prohibited in the H8S/2352, H8S/2394, H8S/2392, and H8S/2390.

PBPCR—Port B MOS Pull-Up Control Register H'FF71

Port B

[On-chip ROM version Only]

Bit	:	7	6	5	4	3	2	1	0
		PB7PCR	PB6PCR	PB5PCR	PB4PCR	PB3PCR	PB2PCR	PB1PCR	PB0PCR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Controls the MOS input pull-up function incorporated into port B on a bit-by-bit basis

Note: Setting is prohibited in the H8S/2352, H8S/2394, H8S/2392, and H8S/2390.

PCPCR—Port C MOS Pull-Up Control Register H'FF72

Port C

[On-chip ROM version Only]

Bit	:	7	6	5	4	3	2	1	0
		PC7PCR	PC6PCR	PC5PCR	PC4PCR	PC3PCR	PC2PCR	PC1PCR	PC0PCR
Initial value	e :	0	0	0	0	0	0	0	0
Read/Write	e :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Controls the MOS input pull-up function incorporated into port C on a bit-by-bit basis

Note: Setting is prohibited in the H8S/2352, H8S/2394, H8S/2392, and H8S/2390.

PDPCR—Port D MOS Pull-Up Control Register H'FF73

Port D

[On-chip ROM version Only]

Bit	:	7	6	5	4	3	2	1	0
		PD7PCR	PD6PCR	PD5PCR	PD4PCR	PD3PCR	PD2PCR	PD1PCR	PD0PCR
Initial value	: :	0	0	0	0	0	0	0	0
Read/Write	e :	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Controls the MOS input pull-up function incorporated into port D on a bit-by-bit basis

Note: Setting is prohibited in the H8S/2352, H8S/2394, H8S/2392, and H8S/2390.

PEPCR—Port E MOS Pull-Up Control Register

H'FF74 Port E

[On-chip ROM version Only]

Bit	:		6	5	4	3	2	1	0
		PE7PCR	PE6PCR	PE5PCR	PE4PCR	PE3PCR	PE2PCR	PE1PCR	PE0PCR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Controls the MOS input pull-up function incorporated into port E on a bit-by-bit basis

Note: Setting is prohibited in the H8S/2352, H8S/2394, H8S/2392, and H8S/2390.

Bit	:	7	6	5	4	3	2	1	0
		_	_	P35ODR	P34ODR	P33ODR	P32ODR	P31ODR	P30ODR
Initial value	:	Undefined	Undefined	0	0	0	0	0	0
Read/Write	:	_	_	R/W	R/W	R/W	R/W	R/W	R/W

Controls the PMOS on/off status for each port 3 pin (P35 to P30)

PAODR—Port A Open Drain Control Register H'FF77 Port A [On-chip ROM version Only]

Bit	Bit :		6	5	4	3	2	1	0
		PA7ODR	PA6ODR	PA5ODR	PA4ODR	PA3ODR	PA2ODR	PA10DR	PA0ODR
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Controls the PMOS on/off status for each port A pin (PA₇ to PA₀)

Note: Setting is prohibited in the H8S/2352, H8S/2394, H8S/2392, and H8S/2390.

Bit :	7		6	5	4		3	2	1	0	
	C/A		CHR	PE	O/E	S ^r	ТОР	MP	CKS	S1 CKS0	
Initial value :	0	,	0	0	0		0	0	0	0	_
Read/Write :	R/W	<u>.</u> .	R/W	_R/W_	R/W	F	R/W	R/W	R/V	W R/W	
Read/While:			Pa (arity Enab O Parit	arity Moo 0 Eve 1 Odo le y bit add	Stop E 0 1 de en parit	Mu C 1 1 stop 2 stop ty	Cl Lultiprocess Multip Multip gth	lock Se 0 0 1 1 0 1 sor Moo process process	ø clock ø/4 clock ø/16 clock ø/64 clock	
		0	8-bit o	data							
		1	7-bit d	data*							

Note: * When 7-bit data is selected, the MSB (bit 7) of TDR is not transmitted.

Asynchronous Mode/Synchronous Mode Select

-	=
0	Asynchronous mode
1	Synchronous mode

- TEND flag generated 12.5 etu after beginning of start bit
- Clock output on/off control only
- 1 GSM mode smart card interface mode operation
 - · TEND flag generated 11.0 etu after beginning of start bit
 - Fixed high/low-level control possible (set in SCR) in addition to clock output on/off control

Note: etu (Elementary Time Unit): Interval for transfer of one bit

Bit	:	7	6	5	4	3	2	1	0
Initial valu	ie:	1	1	1	1	1	1	1	1
Read/Wri	te:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Sets the serial transfer bit rate

Note: See section 14.2.8, Bit Rate Register (BRR), for details.

Bit :	7	6	5	4	3	2		1		0	
	TIE	RIE	TE	RE	MPIE	TEIE		CKE	≣1	CKE0	
Initial value:	0	0	0	0	0	0		0		0	
Read/Write:	R/W_	_R/W_	R/W	R/W	_R/W_	R/W	_	R/V	٧	R/W	
							Clo	ck Er	 nable	9	
							0	0		ynchronous	Internal clock/SCK pin functions as I/O port
									Syr	nchronous de	Internal clock/SCK pin functions as serial clock output
								1	mo		Internal clock/SCK pin functions as clock output*1
									Syr mo	nchronous ode	Internal clock/SCK pin functions as serial clock output
							1	0	Asy mo	ynchronous ide	External clock/SCK pin functions as clock input*2
									mo		External clock/SCK pin functions as serial clock input
								1	mo		External clock/SCK pin functions as clock input*2
									Syr	nchronous ode	External clock/SCK pin functions as serial clock input
						1	Vote:				If the same frequency as the bit rate. h a frequency 16 times the bit rate.
						ansmit	End	Inter	rupt	Enable	
					_ I ⊢	_				,	equest disabled
						1 Tran	nsmi	t end	inte	errupt (TEI) re	equest enabled
				Mu	Itiprocess	or Inter	rupt	Enab	le		
				C	[Cleari	ocesso	lition	s]			
						i the Mi i MPB=				red to 0 eived	
				1	Receiv (ERI) r	equests are dis	full ir s, an	nterru d set	ıpt (F ting	RXI) request of the RDRF	s, receive error interrupt , FER, and ORER flags nultiprocessor bit set to
			Re	ceive Ena	able						
					tion disab	led					
			1	Recep	tion enabl	ed					
		Tr	ansmit En	able							
			Transı	mission di	sabled						
			1 Transı	mission er	nabled						
	Re	ceive Inte	rrupt Enab	ole							
	0		e data full								
		_	e error inte re data full				_				
			e error inte								
Tran	smit Interr	upt Enable	е								

Transmit Interrupt Enable

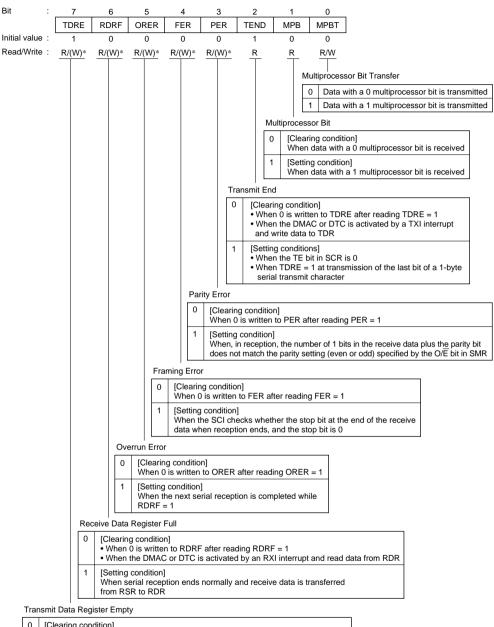
0	Transmit data empty interrupt (TXI) requests disabled
1	Transmit data empty interrupt (TXI) requests enabled

Bit :	7	6	5	4	3	2	2	1	I	0			
	TIE	RIE	TE	RE	MPIE	TE	ΙE	СК	E1 C	KE0			
Initial value:	0	0	0	0	0	0)	C)	0			
Read/Write:	R/W_	R/W_	R/W_	R/W	R/W	R/\	W	<u>R/</u>	W	R/W			
							(Clock E	nable				
								SCMR	SMR		setting	SCK pin function	
								SMIF	C/A,GN	CKE1	CKE0	Cort pin runouon	
								0		Se	ee SCI sp	ecification	
								1	0	0	0	Operates as port input pin	t
								1	0	0	1	Clock output as SCK output pin	
								1	1	0	0	Fixed-low output as SCK output pin	
								1	1	0	1	Clock output as SCK output pin	
								1	1	1	0	Fixed-high output as SCK output pin	
								1	1	1	1	Clock output as SCK output pin	
						ا Transmi	it E	nd Inte	rrupt En	able			
											request di	isabled	
						1 Tra	an	smit end	d interru	pt (TEI)	request e	nabled	
				Mu	ltiproce:	ssor Inte	erri	upt Enal	ble				
				С	-i	iprocess				led			
					[Clea	aring cor	ndi	tions]					
					• Wh	ien the Nien MPB	VIP 3=	1⊑ bit is 1 data is	s receive	ed			
				1		iprocess							
												e error interrupt ind ORER flags	
					in SS	SR are d	lisa					essor bit set to	
					1 is i	received	l .						
				eceive Ena									
					tion disa								
			_1	Recep	tion ena	abled							
		Tra	ansmit En	able									
			Transi	mission dis	sabled								
		_1	Transı	mission er	abled								
	Re	ceive Inte	rrupt Enab	ole									
	0			interrupt (rrupt (ERI									
	1			interrupt (rrupt (ERI									
Trans	smit Interr	upt Enable)					_					
0		data emp		t (TXI) req	uests di	isabled							

Transmit data empty interrupt (TXI) requests enabled

Bit :	7	6	5	4	3	2	1	0
Initial value:	1	1	1	1	1	1	1	1
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

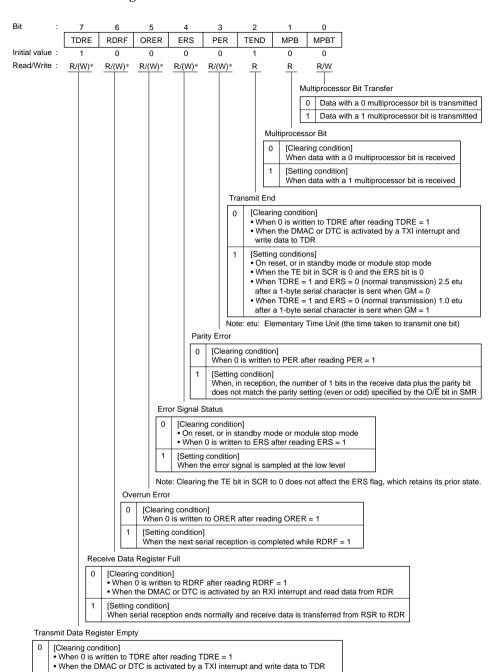
Stores data for serial transmission



0	[Clearing condition] • When 0 is written to TDRE after reading TDRE = 1 • When the DMAC or DTC is activated by a TXI interrupt and write data to TDR
1	[Setting condition] • When the TE bit in SCR is 0 • When data is transferred from TDR to TSR and data can be written to TDR

Note: * Can only be written with 0 for flag clearing.

H'FF7C



Note: * Can only be written with 0 for flag clearing.

. When data is transferred from TDR to TSR and data can be written to TDR

[Setting condition]
• When the TE bit in SCR is 0

RDR0—Receive Data Register 0

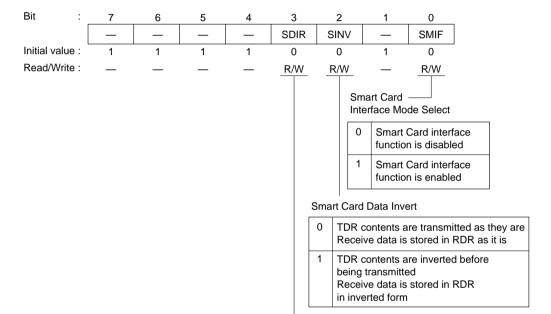
H'FF7D SCI0, Smart Card Interface 0

Bit	:	7	6	5	4	3	2	1	0
Initial va	lue :	0	0	0	0	0	0	0	0
Read/W	rite :	R	R	R	R	R	R	R	R_

Stores received serial data

SCMR0—Smart Card Mode Register 0

H'FF7E SCI0, Smart Card Interface 0



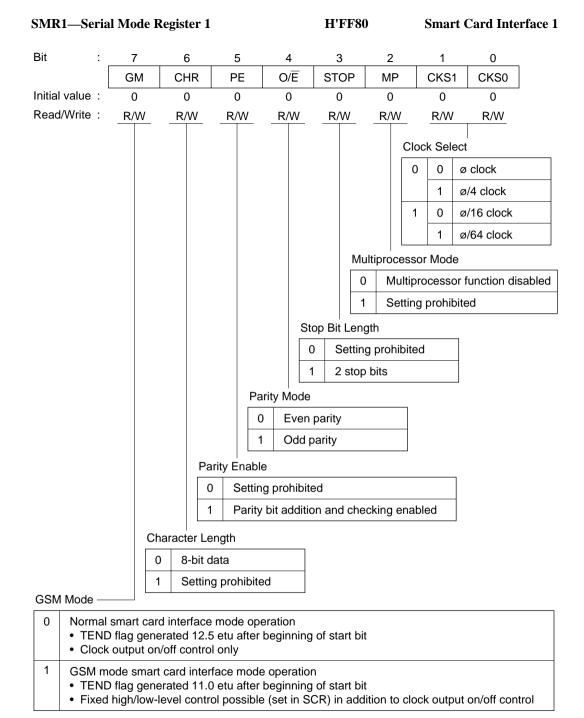
Smart Card Data Direction

0	TDR contents are transmitted LSB-first Receive data is stored in RDR LSB-first
1	TDR contents are transmitted MSB-first Receive data is stored in RDR MSB-first

Bit :	7	6	5	4	3	2	1	0	
	C/A	CHR	PE	O/E	STOP	MP	CKS1	CKS0	
nitial value :	0	0	0	0	0	0	0	0	
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
							ock Sele		
							0	ø clock	
							1	ø/4 clock	
							1 0	ø/16 clock	
							1	ø/64 clock	
					Ми	ultiprocess	or Mode	9	
					С	Multip	rocesso	or function dis	abled
					1	Multip	rocesso	or format sele	cted
				St	op Bit Len	ath			
) 1 stop			7	
					1 2 stop			-	
						, pito			
			Pa	rity Mode					
			C	Even	parity				
			_ _ 1	Odd p	oarity				
		Pa	rity Enable	е					
			Parity	bit addition	on and che	cking disa	abled		
					on and che				
	O.	-							
		naracter Le							
	C								
	_1								
	Note	e: * Whe	n 7-bit data	a is select	ted, the MS	SB (bit 7) o	of TDR is	s not transmit	tted.

Asynchronous Mode/Synchronous Mode Select

0	Asynchronous mode
1	Synchronous mode



Note: etu (Elementary Time Unit): Interval for transfer of one bit

Bit :	7	6	5	4	3	2	1	0
Initial value:	1	1	1	1	1	1	1	1
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	-							

Sets the serial transfer bit rate

Note: See section 14.2.8, Bit Rate Register (BRR), for details.

Bit :	:	7		6		5	4	3	2		1		0		
		TIE	:	RIE		TE	RE	MPIE	TEI	E	СК	E1	CKE0		
Initial value	:	0		0		0	0	0	0		C)	0		
Read/Write		R/V	V	R/M		R/W	R/W	R/W		٧_	R/	W	R/W		
										Clo	ck E	nabl	e e		
										0	0		ynchronou	s Internal clock/S as I/O port	CK pin functions
													nchronous de	Internal clock/S as serial clock	SCK pin functions output
											1		ynchronou ode	s Internal clock/S as clock output	SCK pin functions
													nchronous ode	Internal clock/S as serial clock	SCK pin functions output
										1	0		ynchronou ode	s External clock/s as clock input*	SCK pin functions
													nchronous ode	as serial clock	•
											1	mo	ynchronou ode	as clock input*	
													nchronous ode	External clock/ as serial clock	SCK pin functions input
										Note				k of the same frequ with a frequency 16	
									Transmit	End	Inte	rrupt	Enable		1
														request disabled	
													errupt (TEI	request enabled	
								ultiproces							
								[Clea	processo aring con nen the M	ditio	าร] ์		ared to 0		
									nen MPE						
									processo					ests, receive error in	nterrupt
								(ERI) reques	is, ar	nd se	tting	of the RDI	RF, FER, and ORE	R flags
									eceived	Sabi	ea ui	illi ü	ala Willi liik	e multiprocessor bit	serio
						Re	ceive En	able							
						0	Rece	otion disa	abled						
						1	Rece	otion ena	abled						
					Trans	mit En	able								
					0	Transi	nission d	isabled							
					1	Transi	nission e	nabled							
			Rec	ceive li	nterru	ot Enab	le								
			0				interrupt rrupt (ER								
			1	Rec	eive d	ata full	interrupt rrupt (ER	(RXI) red	quest an	d					
Tra	ans	 smit In	terr.	upt Ena				, 1							
0	$\overline{}$					nterrupt	(TXI) red	uests di	sabled						
1	+						(TXI) red								

Bit :	7	6	5	4	3	2	1	1	0		
	TIE	RIE	TE	RE	MPIE	TEIE	СК	E1 C	KE0		
Initial value:	0	0	0	0	0	0)	0		
Read/Write:	_R/W_	R/W	R/W_	R/W	R/W	R/W	<u>R/</u>	W I	R/W_		
							Clock E	nable			
							SCMR	SMR	SCR	setting	COV min function
							SMIF	C/A,GN	CKE1	CKE0	SCK pin function
							0		Se	ee SCI spe	ecification
							1	0	0	0	Operates as port input pin
							1	0	0	1	Clock output as SCK output pin
							1	1	0	0	Fixed-low output as SCK output pin
							1	1	0	1	Clock output as SCK output pin
							1	1	1	0	Fixed-high output as SCK output pin
							1	1	1	1	Clock output as SCK output pin
					Tr	∣ ansmit l	nd Inte	rrupt En	able		
										request d	isabled
					1					request e	
				Mu	ltiprocess	or Interr	upt Ena	ble			
								ots disab	led		
					When		PIE bit is	s cleared			
					_			ots enab			
					(ERI) re	equests	, and se	tting of t	he RDR	F, FER, a	e error interrupt and ORER flags essor bit set to
					1 is rec						
			Re	eceive Ena	able						
			(tion disabl	ed					
				Recep	tion enable	ed					
		Tr	ansmit En	able							
		C		mission di	sabled						
		1	Trans	mission er	nabled						
	Re	ceive Inte	rrupt Enab	ole			_				
	0				(RXI) requ) request o						
	1				(RXI) requ) request e						
Tran	smit Interr	upt Enable	e								

Transmit data empty interrupt (TXI) requests disabled Transmit data empty interrupt (TXI) requests enabled

Bit :	7	6	5	4	3	2	1	0
Initial value:	1	1	1	1	1	1	1	1
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

:	7 6 5 4 3 2 1 0
	TDRE RDRF ORER FER PER TEND MPB MPBT
al value :	1 0 0 0 1 0 0
nd/Write:	$\frac{R/(W)^*}{ } = \frac{R/(W)^*}{ } = \frac{R/(W)^*}{ } = \frac{R/(W)^*}{ } = \frac{R/(W)^*}{ } = \frac{R/(W)^*}{ } = \frac{R/(W)^*}{ }$
	Multiprocessor Bit Transfer
	0 Data with a 0 multiprocessor bit is transmitte
	1 Data with a 1 multiprocessor bit is transmitte
	Multiprocessor Bit
	0 [Clearing condition] When data with a 0 multiprocessor bit is received
	1 [Setting condition] When data with a 1 multiprocessor bit is received
	Transmit End
	0 [Clearing condition]
	When 0 is written to TDRE after reading TDRE = 1 When the DMAC or DTC is activated by a TXI interrupt
	and write data to TDR
	1 [Setting condition] • When the TE bit in SCR is 0
	When TDRE = 1 at transmission of the last bit of a 1-byte serial transmit character
	Parity Error
	0 [Clearing condition]
	When 0 is written to PER after reading PER = 1
	1 [Setting condition] When, in reception, the number of 1 bits in the receive data plus the parity bit
	does not match the parity setting (even or odd) specified by the O/E bit in SMR
	Framing Error
	0 [Clearing condition] When 0 is written to FER after reading FER = 1
	1 [Setting condition]
	When the SCI checks whether the stop bit at the end of the receive data when reception ends, and the stop bit is 0
	Overrun Error
	0 [Clearing condition]
	When 0 is written to ORER after reading ORER = 1 1 [Setting condition]
	When the next serial reception is completed while RDRF = 1
	Receive Data Register Full
	0 [Clearing condition] • When 0 is written to RDRF after reading RDRF = 1
	When the DMAC or DTC is activated by an RXI interrupt and read data from RDR
	1 [Setting condition] When serial reception ends normally and receive data is transferred
	from RSR to RDR
Transmit	Oata Register Empty
	aring condition] en 0 is written to TDRE after reading TDRE = 1
	en the DMAC or DTC is activated by a TXI interrupt and write data to TDR

Note: * Can only be written with 0 for flag clearing.

• When data is transferred from TDR to TSR and data can be written to TDR

[Setting condition]
• When the TE bit in SCR is 0

Bit :	7	6	5	4	3	2	1	0				
	TDRE	RDRF	ORER	ERS	PER	TEND	MPB	MPBT				
Initial value:	1	0	0	0	0	1	0	0				
Read/Write:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W T				
								Multiprocessor Bit Transfer				
								0 Data with a 0 multiprocessor bit is transmitted				
							1	1 Data with a 1 multiprocessor bit is transmitted				
							ultiproce					
						0		ring condition] n data with a 0 multiprocessor bit is received				
						1	[ng conditions] n data with a 1 multiprocessor bit is received				
					Tr	ansmit End	d					
					0		ing cond					
						• Whe	n the DN	ritten to TDRE after reading TDRE = 1 MAC or DTC is activated by a TXI interrupt a to TDR				
					1	• On re		in standby mode or module stop mode				
								bit in SCR is 0 and the ERS bit is 0 = 1 and ERS = 0 (normal transmission) 2.5 etu				
								e serial character is sent when GM = 0 = 1 and ERS = 0 (normal transmission) 1.0 etu				
								e serial character is sent when GM = 1				
						te: etu: El	ementar	y Time Unit (the time taken to transmit one bit)				
				Pai	rity Error		-1					
					When (ng condition is written	to PER a	after reading PER = 1				
				1		condition]		mber of 1 bits in the receive data plus the parity bit				
								setting (even or odd) specified by the O/E bit in SMR				
			Err	or Signal :	Status							
			0		ng condition							
								odule stop mode ding ERS =1				
			1		condition he error s		npled at	the low level				
			Not	e: Clearin	aring the TE bit in SCR to 0 does not affect the ERS flag, which retains its p							
		Ov	errun Erro	r								
		0		g conditio		after readi	na OREI	R = 1				
		1		condition		artor rodar	9 0					
			When th	ne next se	rial recept	ion is com	pleted w	hile RDRF = 1				
	Re	ceive Data	Register I	Full								
	0	When		n to RDRF		ding RDRF		pt and read data from RDR				
			condition]		s autivated	⊿ υy απ κλ	. menup	pt and read data fidili NDN				
	L				normally	and receive	e data is	transferred from RSR to RDR				
Transmi	t Data Red	gister Emp	ty									

0	[Clearing condition] • When 0 is written to TDRE after reading TDRE = 1 • When the DMAC or DTC is activated by a TXI interrupt and write data to TDR
1	[Setting condition] • When the TE bit in SCR is 0 • When data is transferred from TDR to TSR and data can be written to TDR

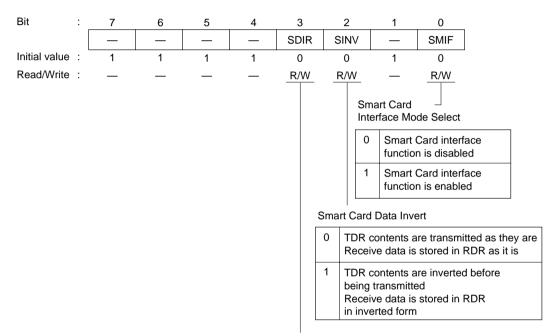
Note: * Can only be written with 0 for flag clearing.

Bit	:	7	6	5	4	3	2	1	0
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R	R	R	R	R	R	R	R

Stores received serial data

SCMR1—Smart Card Mode Register 1

H'FF86 SCI1, Smart Card Interface 1



Smart Card Data Direction

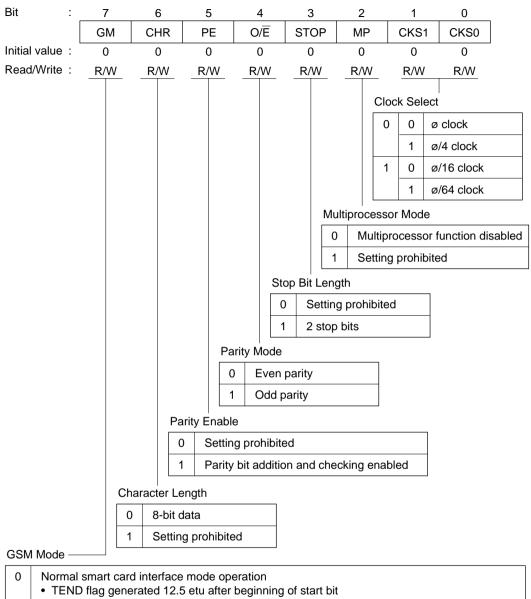
0	TDR contents are transmitted LSB-first Receive data is stored in RDR LSB-first
1	TDR contents are transmitted MSB-first Receive data is stored in RDR MSB-first

Bit :	7		6	5	4	3	3	2		1	0	
	C/A		CHR	PE	O/E	ST	OP	MP	Ck	KS1	CKS0	
Initial value:	0	,	0	0	0	()	0		0	0	
Read/Write :	R/W		R/W	_R/W_	R/W	_R/	W	R/W	R	/W	R/W	
		Chai	Pa (Parity Enabl O Parity Parity	arity Mod D Eve I Odo e v bit addi	Stop Bit 0 1 1 2 le n parity I parity	Mu 0 1 t Leng stop 2 stop	Lultiproces Multi Multi gth bit	lock S 0 0 1 1 0 1 sor Me proces	Selection of the select		
		1	7-bit d	data*		-						
						1						

Note: * When 7-bit data is selected, the MSB (bit 7) of TDR is not transmitted.

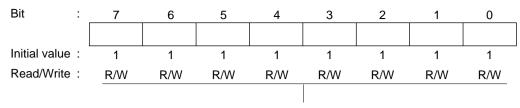
Asynchronous Mode/Synchronous Mode Select

0	Asynchronous mode
1	Synchronous mode



- Clock output on/off control only
- 1 GSM mode smart card interface mode operation
 - TEND flag generated 11.0 etu after beginning of start bit
 - Fixed high/low-level control possible (set in SCR) in addition to clock output on/off control

Note: etu (Elementary Time Unit): Interval for transfer of one bit



Sets the serial transfer bit rate

Note: See section 14.2.8, Bit Rate Register (BRR), for details.

Bit :	7	6	5	4	3	2		1		0	
	TIE	RIE	TE	RE	MPIE	TEIE		CKE	Ξ1	CKE0	
Initial value:	0	0	0	0	0	0		0		0	
Read/Write:	R/W_	_R/W_	R/W	_R/W_	_R/W_	R/W	-	R/V	٧	R/W	
						(Cloc	k En	ا able	 	
							0	0	Asy	ynchronous ode	Internal clock/SCK pin functions as I/O port
									Syı mo	nchronous ode	Internal clock/SCK pin functions as serial clock output
								1	mo		Internal clock/SCK pin functions as clock output*1
									Syı	nchronous ode	Internal clock/SCK pin functions as serial clock output
							1	0	As:	ynchronous ode	External clock/SCK pin functions as clock input*2
									Syı mo	nchronous ode	External clock/SCK pin functions as serial clock input
								1	Asy mo	ynchronous ode	External clock/SCK pin functions as clock input*2
									Syı	nchronous ode	External clock/SCK pin functions as serial clock input
						N	otes				f the same frequency as the bit rate. h a frequency 16 times the bit rate.
					Tra	ansmit E	nd I	nter	rupt	Enable	
					0	Trans	smit	end	inte	errupt (TEI) re	equest disabled
					1	Trans	smit	end	inte	errupt (TEI) re	equest enabled
				Mu	ltiprocesso	or Interru	ıpt E	Enab	le		
				0	ividitipi	ocessor ng condi			ts dis	sabled	
					• When	n the MF	IE I	oit is		ared to 0	
						n MPB= ocessor					
				1	Receiv	e data fu	ıll in	terru	ıpt (l	RXI) requests	s, receive error interrupt
						are disa					, FER, and ORER flags oultiprocessor bit set to
			D.	∟ eceive Ena		eiveu					
					tion disab	led					
					tion enabl	_					
		Tr	l └─ ansmit En								
				mission di	sabled						
		1	Transı	mission er	abled						
	Re	ceive Inte	rrupt Enab	ıle							
			e data full		RXI) requ	est and					
		receive	e error inte	rrupt (ERI) request o	lisabled	-				
_		receive	e error inte								
Trans	smit Interr	upt Enable	е								

0	Transmit data empty interrupt (TXI) requests disabled
1	Transmit data empty interrupt (TXI) requests enabled

Bit :	7	6	5	4	3	2	1	l	0			
	TIE	RIE	TE	RE	MPIE	TEIE	СК	E1 C	KE0			
Initial value:	0	0	0	0	0	0	()	0			
Read/Write:	R/W	R/W	R/W	R/W_	R/W_	R/W	<u>R/</u>	W F	R/W			
							Clock E	nable				
							SCMR	SMR	SCR	setting	OOK air for tier	
							SMIF	C/A,GN	CKE1	CKE0	SCK pin function	
							0		Se	e SCI spe	ecification	
							1	0	0	0	Operates as port input pin	
							1	0	0	1	Clock output as SCK output pin	
							1	1	0	0	Fixed-low output as SCK output pin	
							1	1	0	1	Clock output as SCK output pin	
							1	1	1	0	Fixed-high output as SCK output pin	
							1	1	1	1	Clock output as SCK output pin	
					Tr	ansmit	End Inte	rrupt En	able			
						_				equest d	isabled	
					1	Trar	smit en	d interru	ot (TEI) r	equest e	nabled	
				Mu	ltiprocess	or Interi	upt Ena	ble		-		
					-			ts disab	led			
						n the M	PIE bit is	s cleared				
					_			is receiv				
					Receiv (ERI)	e data f equest	ull interr s, and se	etting of) reques the RDR	F, FER, a	e error interrupt and ORER flags	
					1 is rec		abled ur	itii data i	with the i	muitiproc	essor bit set to	
			Re	eceive Ena	able							
				Recep	tion disabl	ed						
			1	Recep	tion enable	ed						
		Tr	ansmit En	able								
			Trans	mission di	sabled							
		1	Trans	mission er	nabled							
	Receive Interrupt Enable											
		0 Receiv	e data full	interrupt (
		1 Receiv	re data full e error inte	interrupt (RXI) requ	est and						
Trans	smit Inter	rupt Enable		1 - 1 - 1	, - 1							
0		t data emp		t (TXI) req	uests disa	bled						

	0	Transmit data empty interrupt (TXI) requests disabled Transmit data empty interrupt (TXI) requests enabled
ı	1	Transmit data empty interrupt (TXI) requests enabled

Bit	:	7	6	5	4	3	2	1	0
Initial value	:	1	1	1	1	1	1	1	1
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Bit :	7	6	5	4	3	2	1	0		
	TDRE	RDRF	ORER	FER	PER	TEND	MPB	MPBT		
nitial value:	1	0	0	0	0	1	0	0	1	
Read/Write:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W		
							١.	. 4 14:	Dit Tf	
							'	<u> </u>	sor Bit Transfer	
									with a 0 multiprocessor bit is tran	
						١.,	L		with a 1 multiprocessor bit is tran	Similieu
							ultiproce			
						0		ring condition data with a	on] a 0 multiprocessor bit is received	
						1	[ng conditior data with a	n] a 1 multiprocessor bit is received	
					Tra	ansmit En	t			
					0	[[0.04	ng condi			
						• Whe	n the DM		RE after reading TDRE = 1 is activated by a TXI interrupt	
							g conditi			
						• Whe	the TE	bit in SCR	is 0 mission of the last bit of a 1-byte	
								it character		
				Pa	rity Error					
				0		g conditio				
								after reading	g PER = 1	
				1		condition		mber of 1 bit	ts in the receive data plus the par	ty bit
									or odd) specified by the O/E bit i	
			Fra	aming Erro	or					
			0		ng conditio			FED 4		
							ter readii	ng FER = 1		
				When		ecks whetl		top bit at the	e end of the receive	
		Ov	errun Erro	r						
		Го	Clearin	ng condition	n]					
					to ORER	after readi	ng OREI	R = 1		
				condition he next se		ion is com	pleted w	hile RDRF :	= 1	
	Red	ceive Data	Register	Full						
	0		g conditio 0 is writte		after read	ding RDRF	= 1			
								ot and read	data from RDR	
	1	When s		otion ends	normally a	and receiv	e data is	transferred		
		from RS	SR to RDF	₹						
Transmi	t Data Reg	ister Emp	ty						7	
• v	learing con Vhen 0 is v			r reading T	DRE = 1	unt and um				

0	[Clearing condition] • When 0 is written to TDRE after reading TDRE = 1 • When the DMAC or DTC is activated by a TXI interrupt and write data to TDR
1	[Setting condition] • When the TE bit in SCR is 0 • When data is transferred from TDR to TSR and data can be written to TDR

Note: * Can only be written with 0 for flag clearing.

Bit :	7	6	5	4	3	2	1	0
	TDRE	RDRF	ORER	ERS	PER	TEND	MPB	MPBT
nitial value :	1	0	0	0	0	1	0	0
Read/Write:	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W
								 Multiprocessor Bit Transfer
								Data with a 0 multiprocessor bit is transmitted
								Data with a 1 multiprocessor bit is transmitted
						М	ultiproce	ssor Bit
						0	1 [0.04	ring condition] n data with a 0 multiprocessor bit is received
						1		ng conditions] n data with a 1 multiprocessor bit is received
					Tra	ansmit End	d	
					0	• Whe		lition] itten to TDRE after reading TDRE = 1 AAC or DTC is activated by a TXI interrupt
						and v	write data	a to TDR
					1	On reWhenWhenafter	n the TE n TDRE a 1-byte	in standby mode or module stop mode bit in SCR is 0 and the ERS bit is 0 = 1 and ERS = 0 (normal transmission) 2.5 etu serial character is sent when GM = 0
								= 1 and ERS = 0 (normal transmission) 1.0 etu e serial character is sent when GM = 1
					No	te: etu: El	ementar	y Time Unit (the time taken to transmit one bit)
				Pai	rity Error			
				0		g condition is written		after reading PER = 1
				1	When, i		n, the nur	mber of 1 bits in the receive data plus the parity bit setting (even or odd) specified by the O/E bit in SMR
			Ern	or Signal S	Status			
			0	• On re		tandby mo		odule stop mode ding ERS =1
			1		condition		npled at	the low level
			Not	e: Clearin	g the TE b	it in SCR t	o 0 does	s not affect the ERS flag, which retains its prior state.
		Ov	errun Erroi	r				
		0		g conditio is written		after readi	ng ORE	R = 1
		1		condition] ne next se		ion is com	pleted w	hile RDRF = 1
	Red	ceive Data	Register I	Full				
	0	• When		n to RDRF		ding RDRF		at and an addition from DDD
	1		condition		s activated	ı by an RX	ı ınterru	pt and read data from RDR
					normally a	and receive	e data is	transferred from RSR to RDR
Transmi	t Data Reg	jister Emp	ty					
	learing cor		DRE after	reading T	DRE = 1			TDD

0	[Clearing condition] • When 0 is written to TDRE after reading TDRE = 1 • When the DMAC or DTC is activated by a TXI interrupt and write data to TDR
1	[Setting condition] • When the TE bit in SCR is 0 • When data is transferred from TDR to TSR and data can be written to TDR

Note: * Can only be written with 0 for flag clearing.

RDR2—Receive Data Register 2

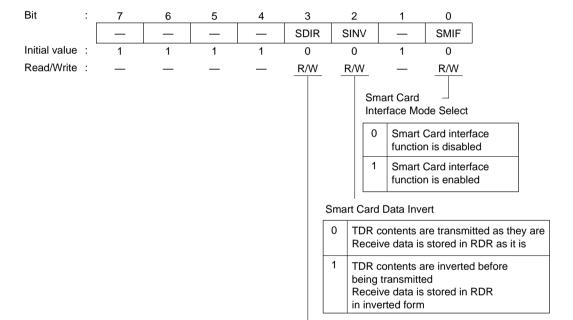
H'FF8D SCI2, Smart Card Interface 2

Bit :	: _	7	6	5	4	3	2	1	0
Initial value :		0	0	0	0	0	0	0	0
Read/Write:		R	R	R	R	R	R	R	R_

Stores received serial data

SCMR2—Smart Card Mode Register 2

H'FF8E SCI2, Smart Card Interface 2



Smart Card Data Direction

0	TDR contents are transmitted LSB-first Receive data is stored in RDR LSB-first
1	TDR contents are transmitted MSB-first Receive data is stored in RDR MSB-first

ADDRAH —	A/D Data Register AH	H'FF90	A/D Converter
ADDRAL —	A/D Data Register AL	H'FF91	A/D Converter
ADDRBH —	A/D Data Register BH	H'FF92	A/D Converter
ADDRBL —	A/D Data Register BL	H'FF93	A/D Converter
ADDRCH —	A/D Data Register CH	H'FF94	A/D Converter
ADDRCL —	A/D Data Register CL	H'FF95	A/D Converter
ADDRDH —	A/D Data Register DH	H'FF96	A/D Converter
ADDRDL —	A/D Data Register DL	H'FF97	A/D Converter

Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
		AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	AD1	AD0	_					_
Initial value	:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Read/Write	:	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R

Stores the results of A/D conversion

Analog Inp	out Channel	A/D Data Register				
Group 0	Group 1					
AN0	AN4	ADDRA				
AN1	AN5	ADDRB				
AN2	AN6	ADDRC				
AN3	AN7	ADDRD				

Bit :	7	6	5	4	3	3	2	1	1	0
	ADF	ADIE	ADST	SCAN	Cł	<s< td=""><td>CH2</td><td>CH</td><td> 1</td><td>CH0</td></s<>	CH2	CH	 1	CH0
Initial value :	0	0	0	0	()	0)	0
Read/Write:	R/(W)*	R/W	R/W	R/W	R/	W	R/W	R/	W	R/W
					Channe	el Selec	ct —			
					Group select		innel lect	Single M	/lode	Group Mode
					CH2	CH1	CH0			· ·
					0	0	0	AN0		AN0
							1	AN1		AN0, AN1
						1	0	AN2		AN0 to AN2
						_	1	AN3		AN0 to AN3
					1	0	0	AN4		AN4
							1	AN5		AN4, AN5
						1	0	AN6		AN4 to AN6
							1	AN7		AN4 to AN7
					Select				_	
				0	Conve	rsion ti	me= 26	6 states	(max.)
				1	Conve	rsion ti	me= 13	4 states	(max.)
			Sc	an Mode						
				Single	mode					
				Scan i	node					
			A/D Start							
			0 A/D	conversio	n stopp	ed				
				gle mode:					ared	to 0
				omatically an mode: A					versio	on continues
			seq	uentially c	n the s	elected	d channe	els until A	ADST	is cleared to
				y software		et, or tra	ansition	to stand	by mo	ode or
			mod	dule stop r	noae					
		A/D Inter	rupt Enable							
			O conversion	n end inte	rrupt (A	ADI) red	quest di	sabled		
A/D End Flag –		1 A/I	O conversion	n end inte	rrupt (A	ADI) red	quest er	nabled		
• When	Clearing conditions] When 0 is written to the ADF flag after reading ADF = 1 When the DTC is activated by an ADI interrupt, and ADDR is read									
1 [Setting • Single	conditions] mode: Whe									

Note: * Can only be written with 0 for flag clearing.

Bit :	7	6	5	4	3	2	1	0
	TRGS1	TRGS0	_	_	_	_	_	_
Initial value :	0	0	1	1	1	1	1	1
Read/Write:	R/W	R/W	_	_	—/(R/W)*	—/(R/W)*	_	_

Timer Trigger Select

TRGS1	TRGS1	Description
0	0	A/D conversion start by external trigger is disabled
	1	A/D conversion start by external trigger (TPU) is enabled
1	0	A/D conversion start by external trigger (8-bit timer) is enabled
	1	A/D conversion start by external trigger pin (ADTRG) is enabled

Note: Applies to the H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, and H8S/2390. These bits are reserved, so should always be written with 1.

DADR0—D/A Data Register 0	
DADR1—D/A Data Register 1	

H'FFA4 H'FFA5 D/A D/A

	:	7	6	5	4	3	2	1	0
Initial value	:	0	0	0	0	0	0	0	0
Read/Write	:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Stores data for D/A conversion

Bit :	7	6	5	4	3	2	1	0	
	DAOE1	DAOE0	DAE	_	_	_	_	_	
Initial value :	0	0	0	1	1	1	1	1	
Read/Write:	R/W	<u>W</u> <u>R/W</u> R/W — — —						_	
		D/A Ou	tput Enab	e 0					
		0 /							
			Channel 0 Analog out						
D/A Output Enable 1									
	0 An	Analog output DA1 is disabled							
	' - '	Channel 1 D/A conversion is enabled Analog output DA1 is enabled							

D/A Conversion Control

DAOE1	DAOE0	DAE	Description
0	0	*	Channel 0 and 1 D/A conversion disabled
	1	0	Channel 0 D/A conversion enabled
			Channel 1 D/A conversion disabled
		1	Channel 0 and 1 D/A conversions enabled
1	0	0	Channel 0 D/A conversion disabled
			Channel 1 D/A conversion enabled
		1	Channel 0 and 1 D/A conversion enabled
	1	*	Channel 0 and 1 D/A conversion enabled

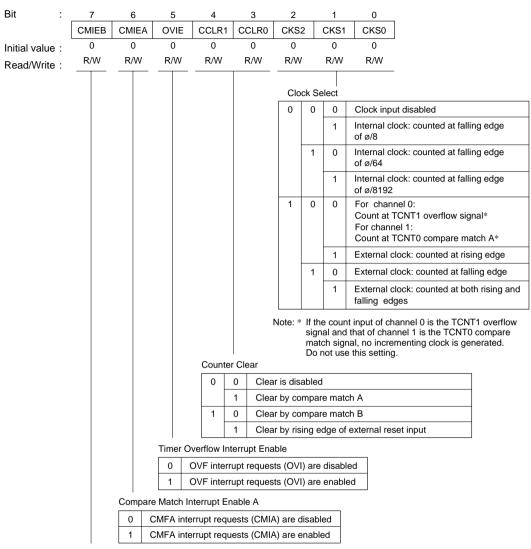
* : Don't care

Bit 7 6 5 4 3 2 1 0 Initial value : 1 0 0 1 0 0 0 0 Read/Write: R/W R/W R/W R/W R/W R R R

Reserved, so should Reserved, so should Reserved, so should always be written with 0. always be written with 1. always be written with 0.

TCR0—Time Control Register 0 TCR1—Time Control Register 1

H'FFB0 H'FFB1 8-Bit Timer Channel 0 8-Bit Timer Channel 1



Compare Match Interrupt Enable B

0	CMFB interrupt requests (CMIB) are disabled
1	CMFB interrupt requests (CMIB) are enabled

TCSR1—Timer Control/Status Register 1 H'FFB3 8-Bit Timer Channel 1 TCSR0 Bit 7 6 5 4 3 2 1 0 CMFB CMFA OVF ADTE OS3 OS2 OS1 OS₀ Initial value: 0 0 0 0 0 0 0 0 Read/Write: R/(W)* R/(W)* R/(W)* R/W R/W R/W R/W R/W TCSR1 Bit 3 2 0 7 6 5 4 1 OVF **CMFB CMFA** OS3 OS₂ OS₁ OS₀ Initial value: 0 0 0 1 0 0 0 0 R/W R/W R/W R/W Read/Write: R/(W)* R/(W)* R/(W)* Output Select -No change when compare match A occurs 1 0 is output when compare match A occurs 1 is output when compare match A occurs Output is inverted when 1 compare match A occurs (toggle output) Output Select 0 0 No change when compare match B occurs 1 0 is output when compare match B occurs 0 1 is output when compare match B occurs 1 1 Output is inverted when compare match B occurs (toggle output) A/D Trigger Enable (TCSR0 only) A/D converter start requests by compare match A are disabled A/D converter start requests by compare match A are enabled Timer Overflow Flag [Clearing condition] Cleared by reading OVF when OVF = 1, then writing 0 to OVF 1 [Setting condition] Set when TCNT overflows (changes from H'FF to H'00) Compare Match Flag A [Clearing condition] • Cleared by reading CMFA when CMFA = 1, then writing 0 to CMFA • When the DTC is activated by a CMIA interrupt, while DISEL bit of MRB in DTC is 0. [Setting condition] Set when TCNT matches TCORA Compare Match Flag B [Clearing condition] • Cleared by reading CMFB when CMFB = 1, then writing 0 to CMFB • When the DTC is activated by a CMIB interrupt, while DISEL bit of MRB in DTC is 0. [Setting condition] Set when TCNT matches TCORB

H'FFB2

8-Bit Timer Channel 0

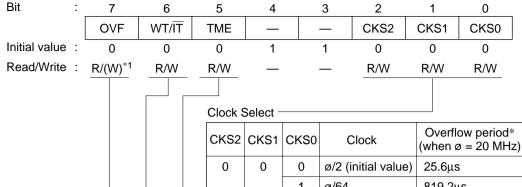
Note: * Only 0 can be written to bits 7 to 5, to clear these flags.

TCSR0—Timer Control/Status Register 0

H'FFB4

8-Bit Timer Channel 0

TCORA0—Time Constant Register A0



1 ø/64 819.2µs 1 0 ø/128 1.6ms 1 ø/512 6.6ms 1 0 0 ø/2048 26.2ms 1 ø/8192 104.9ms 1 0 ø/32768 419.4ms 1 ø/131072 1.68s

Note: * The overflow period is the time from when TCNT starts counting up from H'00 until overflow occurs.

Timer Enable

0	TCNT is initialized to H'00 and halted
1	TCNT counts

Timer Mode Select

0	Interval timer mode: Sends the CPU an interval timer interrupt request (WOVI) when TCNT overflows
1	Watchdog timer mode: Generates the WDTOVF signal*2 when TCNT overflows

Overflow Flag

0	[Clearing condition] Cleared by reading TCSR when OVF = 1, then writing 0 to OVF
1	[Setting condition] Set when TCNT overflows from H'FF to H'00 in interval timer mode

The method for writing to TCSR is different from that for general registers to prevent accidental overwriting. For details see section 13.2.4, Notes on Register Access.

Notes: 1. Can only be written with 0 for flag clearing.

2. The WDTOVF pin function is not available in the F-ZTAT version, H8S/2398, H8S/2394, H8S/2392, or H8S/2390.

Bit :	7	6	5	4	3	2	1	0
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

TCNT is an 8-bit readable/writable*1 up-counter.

Bit :	7	6	5	4	3	2	1	0
	WOVF	RSTE	RSTS	_	_	_	_	_
Initial value :	0	0	0	1	1	1	1	1
Read/Write:	R/(W)*	R/W	R/W	_	_	_	_	_
			Reset Se	elect				
			0 Pc	wer-on re	set			
			1 Ma	anual rese	t*			
		Note: * Manual reset is not supported in the H8S/2357 (F-ZTAT and mask ROM versions) or the H8S/2352, H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392 and H8S/2390. In these models, only 0 should be written to this bit. Reset Enable						
		0	Reset signa	al is not ge	nerated if	TCNT ove	erflows*	
		1 I	Reset signa	al is genera	ated if TCI	NT overflo	WS	
		Note: * The modules H8S/2357 Series are not reset, but TCNT and TCSR in WDT are reset.						

Watchdog Timer Overflow Flag

0	[Clearing condition] Cleared by reading TCSR when WOVF = 1, then writing 0 to WOVF
1	[Setting condition] Set when TCNT overflows (changed from H'FF to H'00) during watchdog timer operation

Note: * Can only be written with 0 for flag clearing.

The method for writing to RSTCSR is different from that for general registers to prevent accidental overwriting. For details see section 13.2.4, Notes on Register Access.

Bit :	7	6	5	4	3	2	1	0
	_	_	CST5	CST4	CST3	CST2	CST1	CST0
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	_	_	R/W	R/W	R/W	R/W	R/W	R/W

Counter Start

0	TCNTn count operation is stopped
1	TCNTn performs count operation

(n = 5 to 0)

Note: If 0 is written to the CST bit during operation with the TIOC pin designated for output, the counter stops but the TIOC pin output compare output level is retained. If TIOR is written to when the CST bit is cleared to 0, the pin output level will be changed to the set initial output value.

TSYR—Timer Synchro Register

H'FFC1

TPU

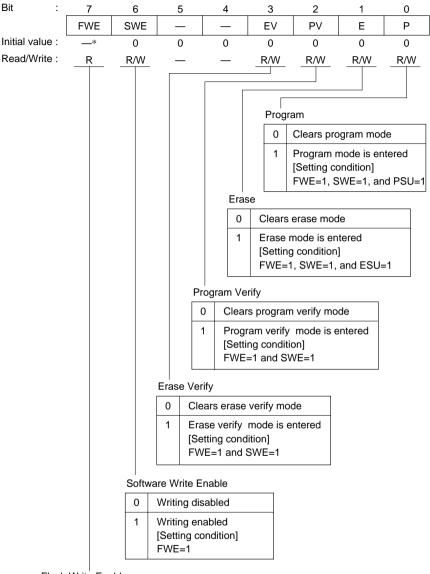
7	6	5	4	3	2	1	0
_	_	SYNC5	SYNC4	SYNC3	SYNC2	SYNC1	SYNC0
0	0	0	0	0	0	0	0
_	_	R/W	R/W	R/W	R/W	R/W	R/W
		- : 0					
		Timer S	ynchroniza	ation —			
	7 0 	7 6 — — — 0 0 — —	- SYNC5 0 0 0 - R/W	— — SYNC5 SYNC4 0 0 0 0 — — R/W R/W	— SYNC5 SYNC4 SYNC3 0 0 0 0 0	— SYNC5 SYNC4 SYNC3 SYNC2 0 0 0 0 0 — — R/W R/W R/W R/W	— — SYNC5 SYNC4 SYNC3 SYNC2 SYNC1 0 0 0 0 0 0 0 — — R/W R/W R/W R/W R/W

0	TCNTn operates independently (TCNT presetting/ clearing is unrelated to other channels)
1	TCNTn performs synchronous operation TCNT synchronous presetting/synchronous clearing is possible

(n = 5 to 0)

- Notes: 1. To set synchronous operation, the SYNC bits for at least two channels must be set to 1.
 - 2. To set synchronous clearing, in addition to the SYNC bit, the TCNT clearing source must also be set by means of bits CCLR2 to CCLR0 in TCR.

(for the H8S/2357F-ZTAT)

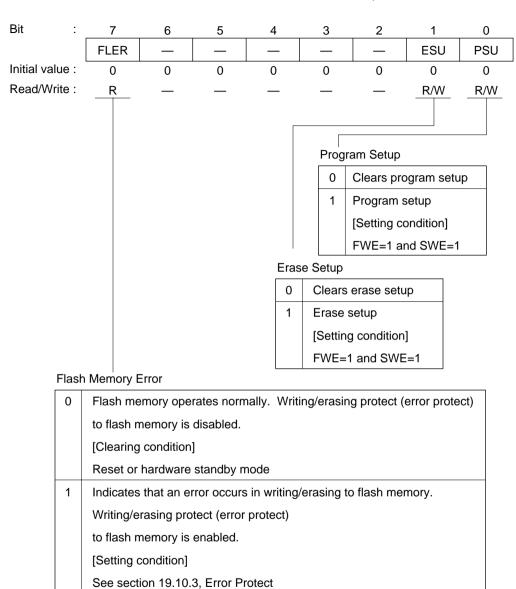


Flash Write Enable

0	When a low level is input to the FWE pin (hardware protect state)
1	When a high level is input to the FWE pin

Note: * Determined by the state of the FWE pin.

(for the H8S/2357F-ZTAT)



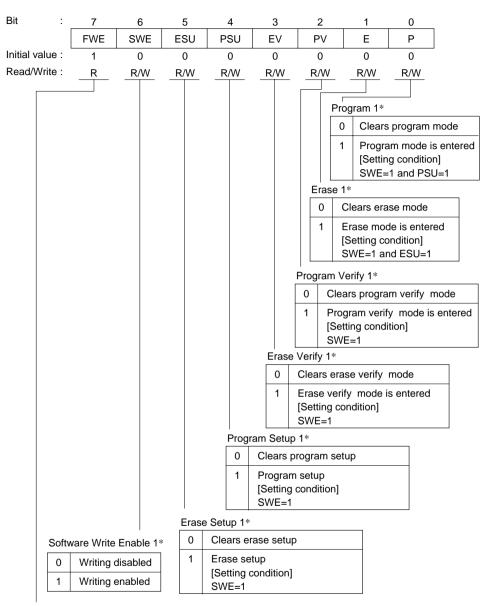
EBR1—Erase Block Specification Register 1	H'FFCA	FLASH
		(for the H8S/2357F-ZTAT)
EBR2— Erase Block Specification Register 2	H'FFCB	FLASH
		(for the H8S/2357F-ZTAT)

Bit :	7	6	5	4	3	2	1	0
EBR1	_		_	_	_	_	EB9	EB8
Initial value :	0	0	0	0	0	0	0	0
Read/Write:	_	_	_	_	_	_	R/W	R/W
Bit :	7	6	5	4	3	2	1	0
EBR2	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0
Initial value :	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Deviding Erase Blocks

Block (size)	Address
EB0 (1k byte)	H'000000 to H'0003FF
EB1 (1k byte)	H'000400 to H'0007FF
EB2 (1k byte)	H'000800 to H'000BFF
EB3 (1k byte)	H'000C00 to H'000FFF
EB4 (28k bytes)	H'001000 to H'007FFF
EB5 (16k bytes)	H'008000 to H'00BFFF
EB6 (8k bytes)	H'00C000 to H'00DFFF
EB7 (8k bytes)	H'00E000 to H'00FFFF
EB8 (32k bytes)	H'010000 to H'017FFF
EB9 (32k bytes)	H'018000 to H'01FFFF

(for the H8S/2398F-ZTAT)



Flash Write Enable

Always read as 1. Writing is disabled.

Note: * The target address is H'000000 to H'03FFFF.

(for the H8S/2398F-ZTAT)

Bit	:	7	6	5	4	3	2	1	0
		FLER	_	_	_	_	_	_	_
Initial valu	ue:	0	0	0	0	0	0	0	0
Read/Wri	ite:	R	_				_	_	_

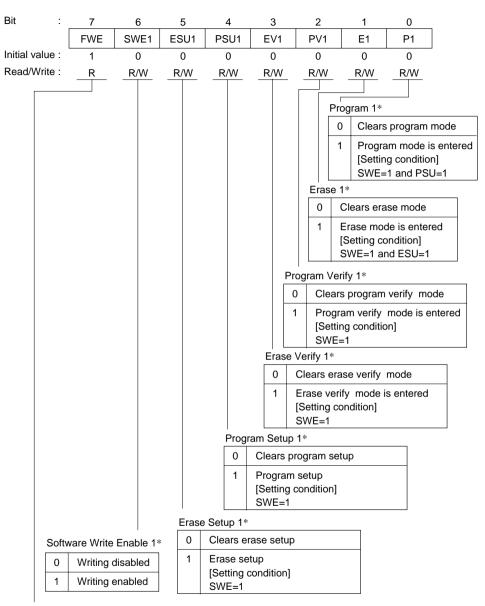
Flash Memory Error

0	Flash memory operates normally. Writing/erasing protect (error protect)
	to flash memory is disabled.
	[Clearing condition]
	Reset or hardware standby mode
1	Indicates that an error occurs in writing/erasing to flash memory.
	Writing/erasing protect (error protect)
	to flash memory is enabled.
	[Setting condition]
	See section 19.19.3, Error Protect

EBR1—Erase Block Specification Register 1	H'FFCA	FLASH
		(for the H8S/2398F-ZTAT)
EBR2—Erase Block Specification Register 2	H'FFCB	FLASH
		(for the H8S/2398F-ZTAT)

Bit :	7	6	5	4	3	2	1	0
EBR1	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0
Initial value :	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit :	7	6	5	4	3	2	1	0
EBR2	_	_	_	_	EB11	EB10	EB9	EB8
Initial value :	0	0	0	0	0	0	0	0
Read/Write:		_		_	R/W	R/W	R/W	R/W

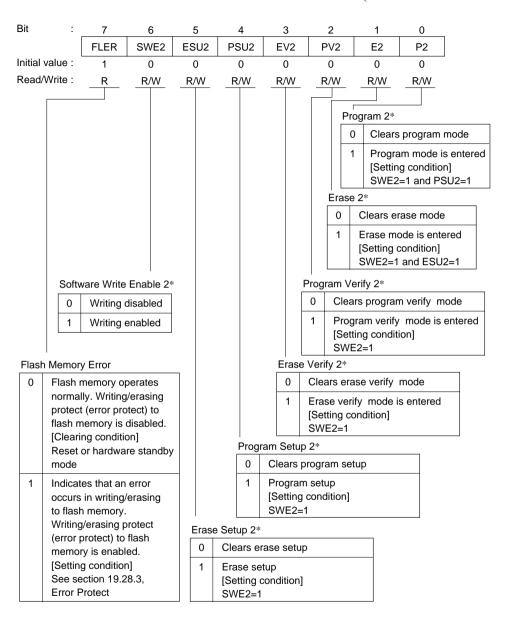
(for the H8S/2395F-ZTAT)



Flash Write Enable

Always read as 1. Writing is disabled.

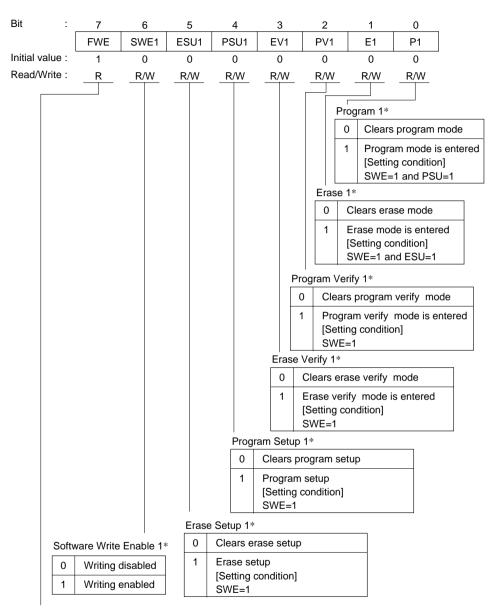
Note: * The target address is H'000000 to H'03FFFF.



Note: * The target address is H'040000 to H'05FFFF.

EBR1—Erase Block Specification Register 1	H'FFCA	FLASH
		(for the H8S/2395F-ZTAT)
EBR2—Erase Block Specification Register 2	H'FFCB	FLASH
		(for the H8S/2395F-ZTAT)

Bit :	7	6	5	4	3	2	1	0		
EBR1	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0		
Initial value :	0	0	0	0	0	0	0	0		
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
Bit :	7	6	5	4	3	2	1	0		
EBR2	_	_	EB13	EB12	EB11	EB10	EB9	EB8		
Initial value :	0	0	0	0	0	0	0	0		
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Reser	ved bits								
Write as 0.										

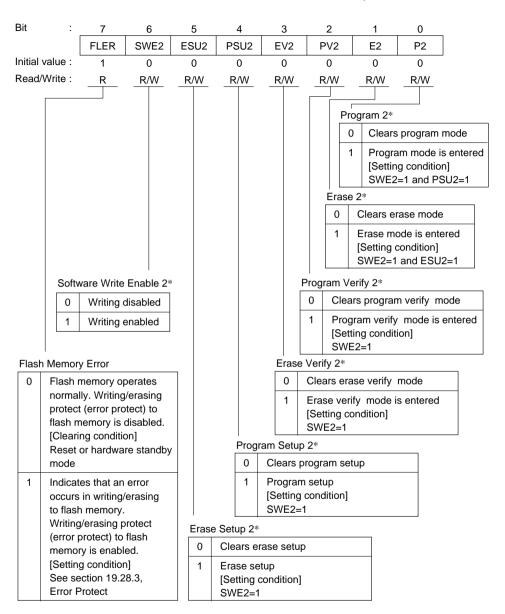


Flash Write Enable

Always read as 1. Writing is disabled.

Note: * The target address is H'000000 to H'03FFFF.

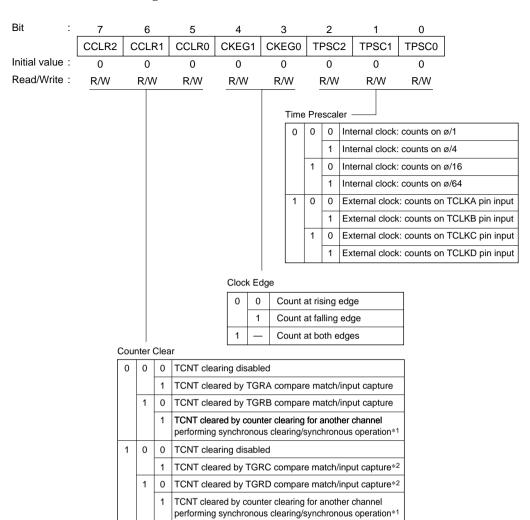
(for the H8S/2396F-ZTAT)



Note: * The target address is H'040000 to H'07FFFF.

EBR1—Erase Block Specification Register 1	H'FFCA	FLASH
		(for the H8S/2396F-ZTAT)
EBR2—Erase Block Specification Register 2	H'FFCB	FLASH
		(for the H8S/2396F-ZTAT)

Bit :	7	6	5	4	3	2	1	0
EBR1	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0
Initial value :	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Bit :	7	6	5	4	3	2	1	0
EBR2	EB15	EB14	EB13	EB12	EB11	EB10	EB9	EB8
Initial value :	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W



Notes: 1. Synchronous operation setting is performed by setting the SYNC bit in TSYR to 1.

When TGRC or TGRD is used as a buffer register, TCNT is not cleared because the buffer register setting has priority, and compare match/input capture does not occur.

Bit :	7	6	5	4	3	2	2		1	0	
	_	_	BFB	BFA	MD3	MI)2	М	D1	MD0	
Initial value:	1	1	0	0	0		0		0	0	
Read/Write:	_	_	R/W	R/W	R/W	R/	W	R	/W	R/W	
					М	ode –					
						0 0	0	0	Norm	al operation	ı
								1	Rese	ved	
							1	0	PWM	mode 1	
								1	PWM	mode 2	
						1	0	0	Phase	e counting r	node 1
								1	Phase	e counting r	node 2
							1	0	Phase	e counting r	node 3
								1	Phase	e counting r	node 4
						1 *	*	*	_		
										* : D	on't care
					No	tes: 1				ed bit. In a	
						2				e written w mode cann	
							set f	or cha	annels	0 and 3. In	n this
							case MD2		nould a	always be w	ritten to
				TGRA E	Buffer Opera	ation					
				0 T	GRA opera	ates no	rmall	у			
				1 T	GRA and T	GRC	used	toget	her		
				fo	or buffer op	eratio	1				
			TGRB B	uffer Opera	tion						
							_				

0	TGRB operates normally
1	TGRB and TGRD used together for buffer operation

Bit :	7	6	5	4		3		2	1	0		
	IOB3	IOB2	IOB1	IOB0	IC)A3		IOA2	IOA1	IOA0		
Initial value:	0	0	0	0		0		0	0	0		
Read/Write:	R/W	R/W	R/W	R/W	R	/W		R/W	R/W	R/W		
TGR0A I/O Control												
				0	0	0	0	TGR0A		ıt disabled		
							1	is outpu compar	e Initial	output is	0 output at compare match	
						1	0	register	0 outpu	out	1 output at compare match	
							1				Toggle output at compare match	
					1	0	0		Outpu	ıt disabled		
							1			output is	0 output at compare match	
						1	0		1 outp	out	1 output at compare match	
							1				Toggle output at compare match	
				1	0	0	0	TGR0A		re input	Input capture at rising edge	
							1	is input capture	sourc	e is 40 pin	Input capture at falling edge	
						1	*	register		·	Input capture at both edges	
					1	*	*			re input e is channel	Input capture at TCNT1 count-up/	

TGR0B I/O Control

* : Don't care

0	0	0	0	TGR0B	Output disabled			
			1	is output compare	Initial output is	0 output at compare match		
		1	0	register	0 output	1 output at compare match		
			1			Toggle output at compare match		
	1	0	0		Output disabled			
			1		Initial output is	0 output at compare match		
		1	0		0 output	1 output at compare match		
			1			Toggle output at compare match		
1	0	0	0	TGR0B	Capture input	Input capture at rising edge		
			1	is input capture	source is TIOCB0 pin	Input capture at falling edge		
		1	*	register	-	Input capture at both edges		
	1	*	*		Capture input source is channel 1/count clock	Input capture at TCNT1 count-up/ count-down* ¹		

* : Don't care

1/count clock

Note: *1. When bits TPSC2 to TPSC0 in TCR1 are set to B'000, and ø/1 is used as the TCNT1 count clock, this setting is invalid and input capture is not generated.

Bit :	7	6	5	4	3	2	1	0
:	IOD3	IOD2	IOD1	IOD0	IOC3	IOC2	IOC1	IOC0
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

TGR0C I/O Control

			-				
)	0	0	0	TGR0C	Output disabled	
				1	is output compare	Initial output is 0 output	0 output at compare match
			1	0	register	σοιιραί	1 output at compare match
				1			Toggle output at compare match
		1	0	0		Output disabled	
				1		Initial output is	0 output at compare match
			1	0		1 output	1 output at compare match
				1			Toggle output at compare match
1	1	0	0	0	TGR0C	Capture input	Input capture at rising edge
				1	is input capture	source is TIOCC0 pin	Input capture at falling edge
			1	*	register		Input capture at both edges
		1	*	*		Capture input source is channel 1/count clock	Input capture at TCNT1 count-up/ count-down

* : Don't care

Note: When the BFA bit in TMDR0 is set to 1 and TGR0C is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

TGR0D I/O Control

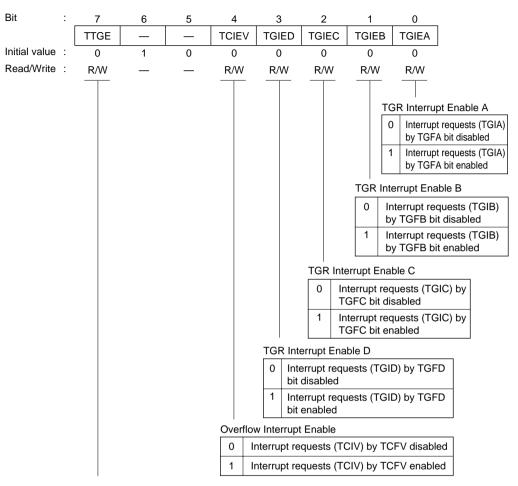
			• · · · · ·								
0	0	0	0	TGR0D	Output disabled						
			1	is output compare	Initial output is	0 output at compare match					
		1	0	register	0 output	1 output at compare match					
			1	-		Toggle output at compare match					
	1	0	0		Output disabled						
			1		Initial output is	0 output at compare match					
		1	0		1 output	1 output at compare match					
			1			Toggle output at compare match					
1	0	0	0	TGR0D	Capture input	Input capture at rising edge					
			1	is input capture	source is TIOCD0 pin	Input capture at falling edge					
		1	*	register *2		Input capture at both edges					
	1	*	*	_	Capture input source is channel 1/count clock	Input capture at TCNT1 count-up/count-down*1					

*: Don't car

Notes: 1. When bits TPSC2 to TPSC0 in TCR1 are set to B'000, and ø/1 is used as the TCNT1 count clock, this setting is invalid and input capture is not captured.

When the BFB bit in TMDR0 is set to 1 and TGR0D is used as a buffer register, this setting is invalid and input capture/output compare is not generated.

Note: When TGRC or TGRD is designated for buffer operation, this setting is invalid and the register operates as a buffer register.



A/D Conversion Start Request Enable

0	A/D conversion start request generation disabled
1	A/D conversion start request generation enabled

Bit :		7	6	5	4		3		2	1		0	_
	_		-	_	TCF	v -	TGFD	TO	GFC	TGF	-в	TGF	A
Initial value :		1	1	0	0		0		0	0		0	
Read/Write:	-	_	_	_	R/(W)* F 	R/(W)	* R/	(W)*	R/(V	V)*	R/(W)	* -
												Input	Capture/Output Compare Flag A
												0	[Clearing condition] • When DTC is activated by TGIA interrupt while DISEL bit of MRB in DTC is 0 • When DMAC is activated by TGIA interrupt while DTA bit of DMABCR in DMAC is 1 • When 0 is written to TGFA after reading TGFA = 1
												1	[Setting conditions] • When TCNT = TGRA while TGRA is functioning as output compare register • When TCNT value is transferred to TGRA by input capture signal while TGRA is functioning as input capture register
										Inpu	ıt Ca	pture/C	Output Compare Flag B
										0	• '	When I	condition] DTC is activated by TGIB interrupt while DISEL bit 3 in DTC is 0
										1	+		is written to TGFB after reading TGFB = 1
											• 1	When output of When of When	conditions] ICNT = TGRB while TGRB is functioning as compare register ICNT value is transferred to TGRB by input signal while TGRB is functioning as input capture
								Input	Captu	ıre/Ou	ıtput	Compa	are Flag C
								0	[Clea	aring c en DT C is 0	condi FC is	ition] activat	ed by TGIC interrupt while DISEL bit of MRB in TGFC after reading TGFC = 1
								1	[Setti	ing co	nditi	ions]	C while TGRC is functioning as output compare
									• Wh				s transferred to TGRC by input capture signal ioning as input capture register
						1	ı nput (Captur	e/Outr	out Co	mpa	re Flag	
						Ī	0		ring co				
								• Whe	n DTC	c is ac	tivat	ed by 7	GID interrupt while DISEL bit of MRB in DTC
									n 0 is	writte	n to	TGFD	after reading TGFD = 1
							1	• Whe	n TCN	NT = T NT valu	GRI ue is	transfe	TGRD is functioning as output compare register erred to TGRD by input capture signal while it capture register
					Overf		lag						
					0	[Clea	aring (conditi		CFV a	ıfter ı	reading	TCFV = 1
					1	[Sett	ing co	onditio	ns]				
						Whe	n the	ICNT	value	overfl	lows	(chan	ges from H'FFFF to H'0000)

Note: * Can only be written with 0 for flag clearing.

Bit

Read/Write:

Up-counter

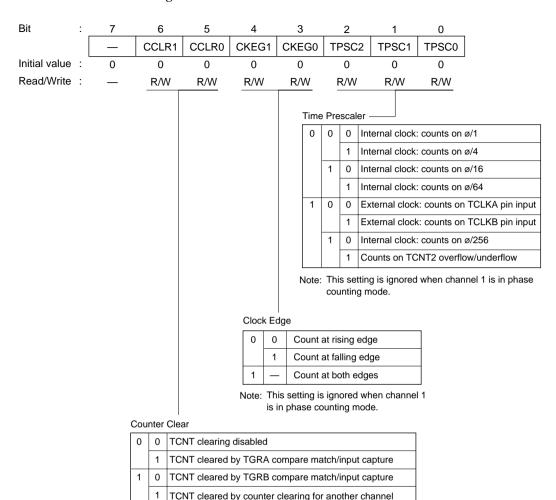
 TPU0

TGR0A—Timer General Register 0A H'FFD8 TPU0 TGR0B—Timer General Register 0B **TPU0 H'FFDA** TGR0C—Timer General Register 0C **H'FFDC TPU0** TGR0D—Timer General Register 0D **TPU0 H'FFDE**

Bit

Initial value:

Initial value:



Note: * Synchronous operating setting is performed by setting the SYNC bit in TSYR to 1.

performing synchronous clearing/synchronous operation*

Bit :	7	6	5	4	3	2	1	0
	_	_	_	_	MD3	MD2	MD1	MD0
Initial value :	1	1	0	0	0	0	0	0
Read/Write:	_			_	R/W	R/W	R/W	R/W

∕lode	

Widde											
0	0	0	0	Normal operation							
			1	Reserved							
		1	0	PWM mode 1							
			1	PWM mode 2							
	1	0	0	Phase counting mode 1							
			1	Phase counting mode 2							
		1	0	Phase counting mode 3							
			1	1Phase counting mode 4							
1	*	*	*	_							

*: Don't care

Notes: MD3 is a reserved bit. In a write, it should always be written with 0.

Bit	Bit :		6	5	4	3	2	1	0
		IOB3	IOB2	IOB1	IOB0	IOA3	IOA2	IOA1	IOA0
Initial value	: '	0	0	0	0	0	0	0	0
Read/Write:		R/W R/W		R/W	R/W	R/W	R/W	R/W	R/W
					TGR1				

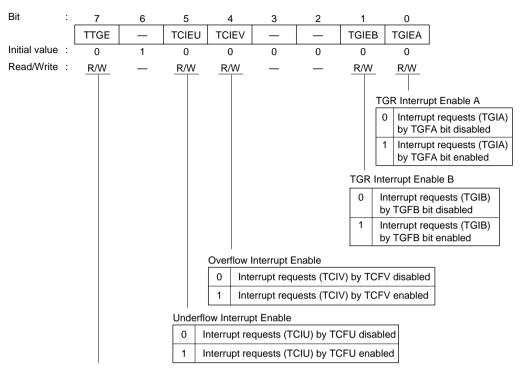
0	0	0	0	TGR1A	Output disabled						
			1	is output compare	Initial output is	0 output at compare match					
		1	0	register	0 output	1 output at compare match					
			1			Toggle output at compare match					
	1	0	0		Output disabled						
			1		Initial output is	0 output at compare match					
		1	0		1 output	1 output at compare match					
			1			Toggle output at compare match					
1	0	0	0	TGR1A	Capture input	Input capture at rising edge					
			1	is input capture	source is TIOCA1 pin	Input capture at falling edge					
		1	*	register		Input capture at both edges					
	1	*	*		Capture input source is TGR0A compare match/ input capture	Input capture at generation of channel 0/TGR0A compare match/input capture					

* : Don't care

TGR1B I/O Control

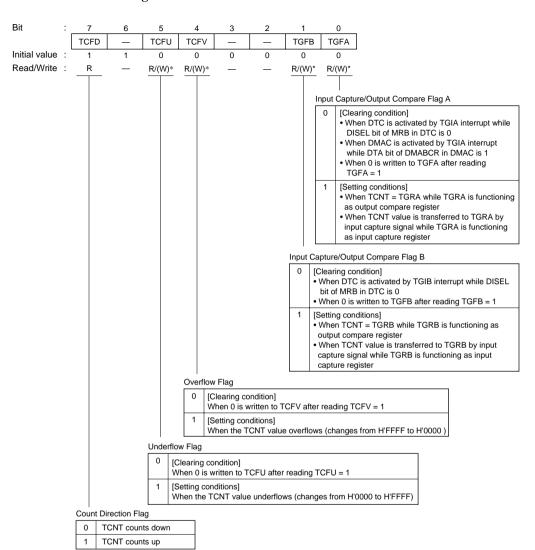
_													
	0	0	0	0	TGR1B	Output disabled							
				1	is output compare	Initial output is	0 output at compare match						
			1	0	register	0 output	1 output at compare match						
				1			Toggle output at compare match						
		1	0	0		Output disabled							
				1		Initial output is	0 output at compare match						
			1	0		1 output	1 output at compare match						
				1			Toggle output at compare match						
ſ	1	0	0	0	TGR1B	Capture input	Input capture at rising edge						
				1	is input capture	source is TIOCB1 pin	Input capture at falling edge						
			1	*	register	·	Input capture at both edges						
		1	*	*		Capture input source is TGR0C compare match/ input capture	Input capture at generation of TGR0B compare match/input capture						

* : Don't care



A/D Conversion Start Request Enable

ſ	0	A/D conversion start request generation disabled
	1	A/D conversion start request generation enabled



Note: * Can only be written with 0 for flag clearing.

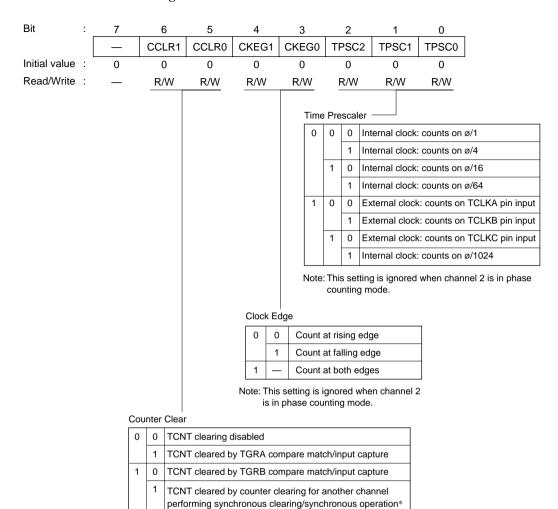
Bit Initial value : O O O O O O

Up/down-counter*

Note: * This timer counter can be used as an up/down-counter only in phase counting mode or when performing overflow/underflow counting on another channel. In other cases it functions as an up-counter.

TGR1A—Timer General Register 1A							H'FFE8							TP			
TGR1B—Timer General Register 1B							H'FFEA							TP			
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0

Initial value :



Note: * Synchronous operating setting is performed by setting the SYNC bit TSYR to 1.

Bit :	7	6	5	4	3	2	1	0	
	_	_	_	_	MD3	MD2	MD1	MD0	
Initial value :	1	1	0	0	0	0	0	0	
Read/Write:	_	_	_	_	R/W	R/W	R/W	R/W	

Mode									
	0	0	0	0	Normal operation				
				1	Reserved				
			1	0	PWM mode 1				
				1	PWM mode 2				
		1	0	0	Phase counting mode 1				
				1	Phase counting mode 2				
			1	0	Phase counting mode 3				
				1	Phase counting mode 4				

*: Don't care

Notes: MD3 is a reserved bit. In a write, it should always be written with 0.

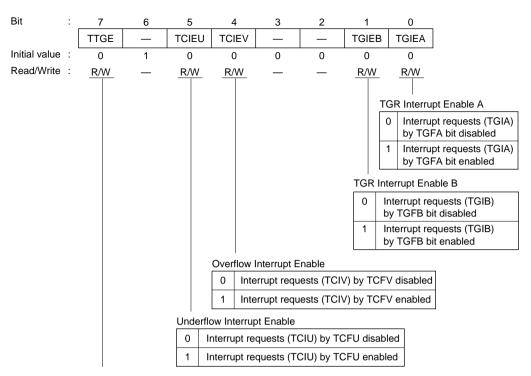
Bit :	7	6	5	4		3		2	1	0	_
	IOB3	IOB2	IOB1	IOB0	1	OA3		IOA2	IOA1	IOA0	
Initial value:	0	0	0	0		0		0	0	0	-
Read/Write:	R/W	R/W	R/W	R/W	_!	R/W		R/W	R/W	R/W	
TGR2A I/O Control											
				0	0	0	0	TGR2A	Output	disabled	
							1	is output compare	Initial c	output is	0 output at compare match
						1	0	register	0 outp	ut	1 output at compare match
							1				Toggle output at compare match
					1	0	0		Output	disabled	
							1			output is	0 output at compare match
						1	0		1 outpi	ut	1 output at compare match
							1				Toggle output at compare match
				1	*	0	0	TOREA Captaic input			Input capture at rising edge
							1	is input capture	source		Input capture at falling edge
						1	*	register	F		Input capture at both edges

* : Don't care

TGR2B I/O Control

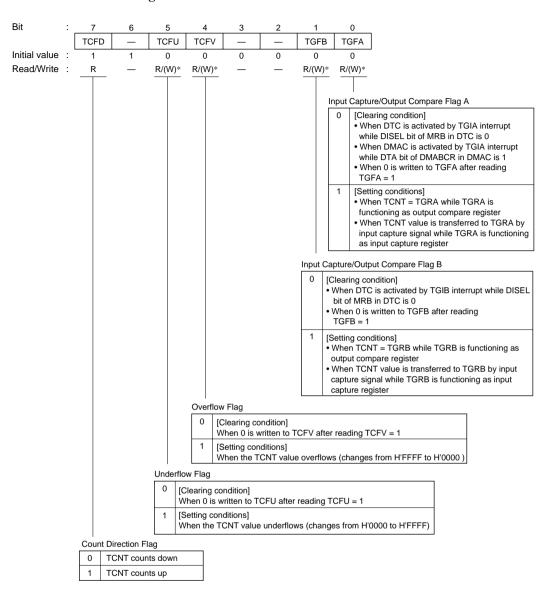
TGK2B #O CONTO													
0	0	0	0	TGR2B	Output disabled								
			1	is output compare	Initial output is	0 output at compare match							
		1	0	register	0 output	1 output at compare match							
			1			Toggle output at compare match							
	1	0	0		Output disabled								
			1		Initial output is	0 output at compare match							
		1	0		1 output	1 output at compare match							
			1			Toggle output at compare match							
1	*	0	0	TGR2B	Capture input	Input capture at rising edge							
			1	is input capture	source is TIOCB2 pin	Input capture at falling edge							
		1	*	register	·	Input capture at both edges							

* : Don't care

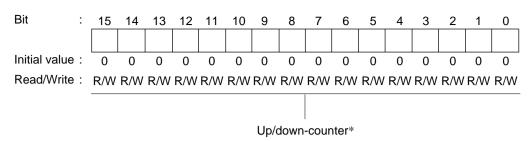


A/D Conversion Start Request Enable

0	A/D conversion start request generation disabled
1	A/D conversion start request generation enabled



Note: * Can only be written with 0 for flag clearing.



Note: * This timer counter can be used as an up/down-counter only in phase counting mode or when performing overflow/underflow counting on another channel. In other cases it functions as an up-counter.

TGR2A—Timer General Register 2A							H'FFF8							TPU2			
TGR2B—Timer General Register 2B							H'FFFA							TPU2			
Bit	:	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0

Initial value: 1 1 1 1 1 1 1 1 1

Read/Write:

Appendix C I/O Port Block Diagrams

C.1 Port 1 Block Diagram

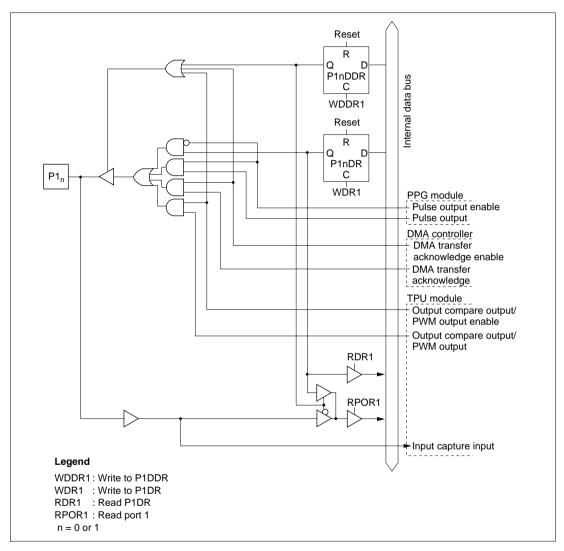


Figure C-1 (a) Port 1 Block Diagram (Pins P1₀ and P1₁)

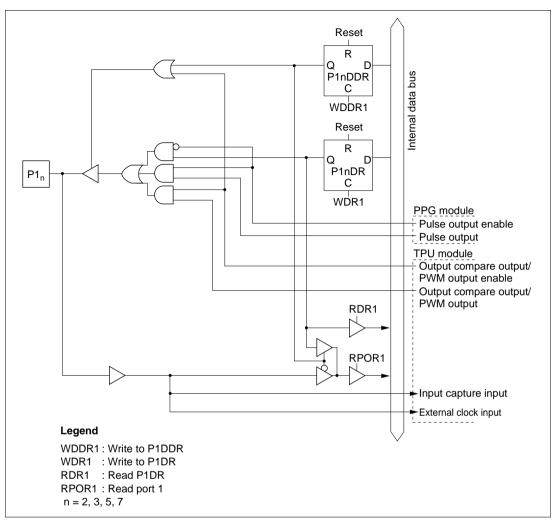


Figure C-1 (b) Port 1 Block Diagram (Pins P1₂, P1₃, P1₅, and P1₇)

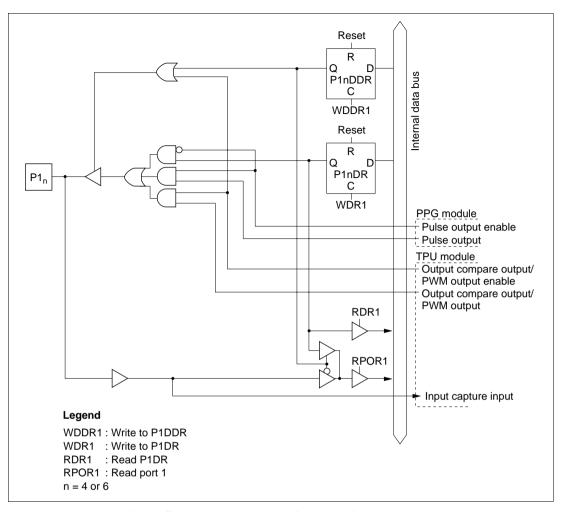


Figure C-1 (c) Port 1 Block Diagram (Pins $P1_4$ and $P1_6$)

C.2 Port 2 Block Diagram

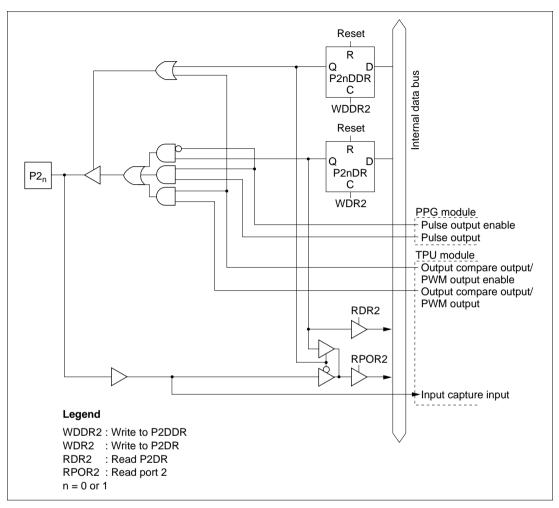


Figure C-2 (a) Port 2 Block Diagram (Pins P2₀ and P2₁)

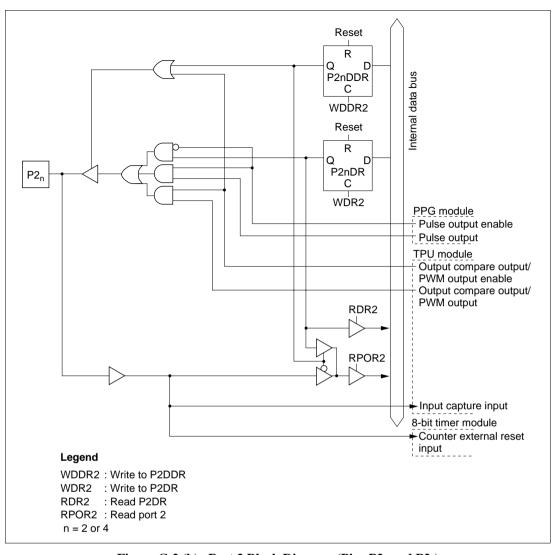


Figure C-2 (b) Port 2 Block Diagram (Pins $P2_2$ and $P2_4$)

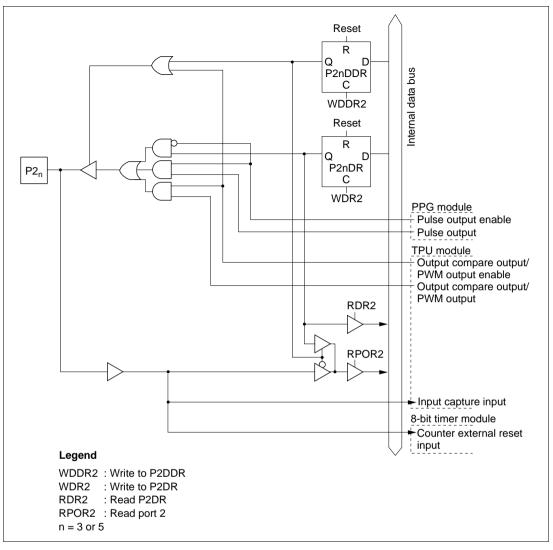
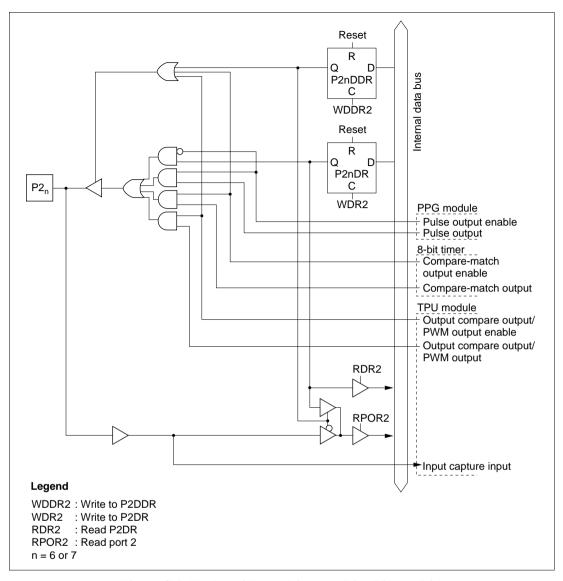


Figure C-2 (c) Port 2 Block Diagram (Pins P2, and P2,)



 $Figure~C-2~(d)~~Port~2~Block~Diagram~(Pins~P2_6~and~P2_7)\\$

C.3 Port 3 Block Diagram

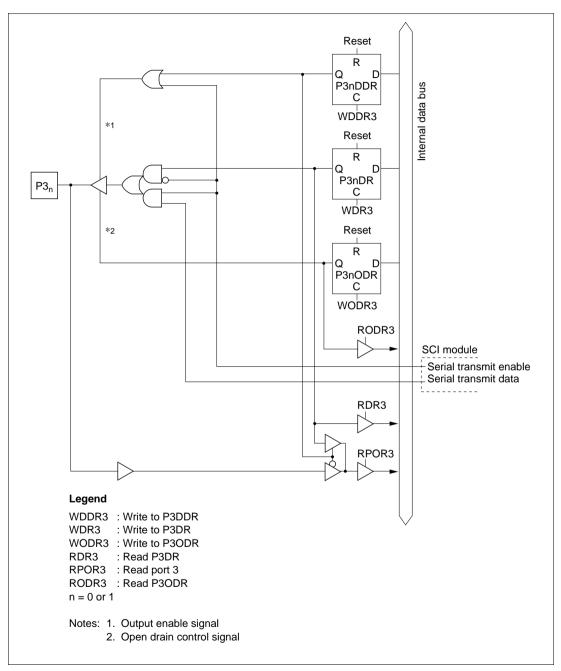


Figure C-3 (a) Port 3 Block Diagram (Pins P3₀ and P3₁)

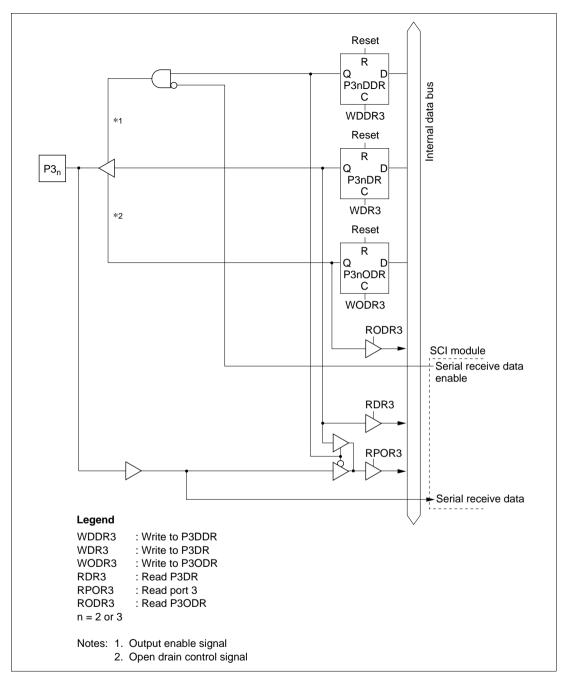


Figure C-3 (b) Port 3 Block Diagram (Pins $P3_2$ and $P3_3$)

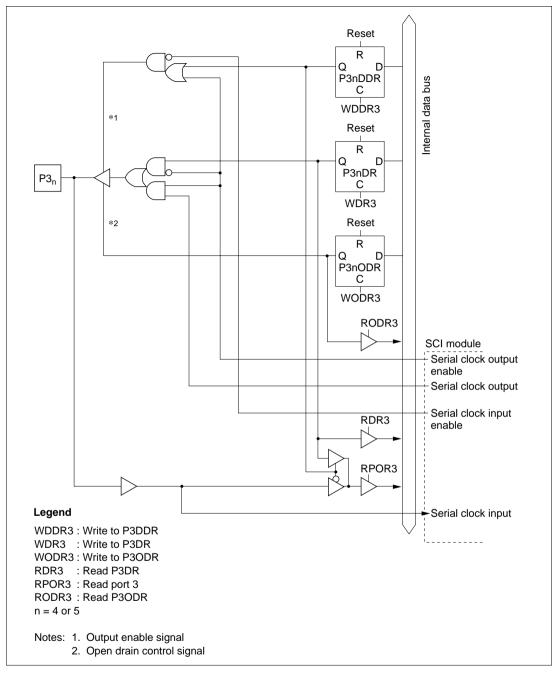


Figure C-3 (c) Port 3 Block Diagram (Pins P3₄ and P3₅)

C.4 Port 4 Block Diagram

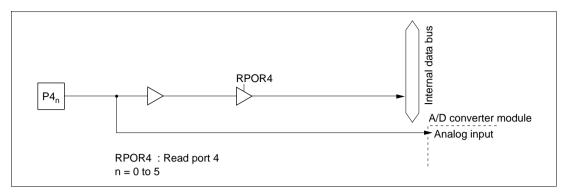


Figure C-4 (a) Port 4 Block Diagram (Pins P4₀ to P4₅)

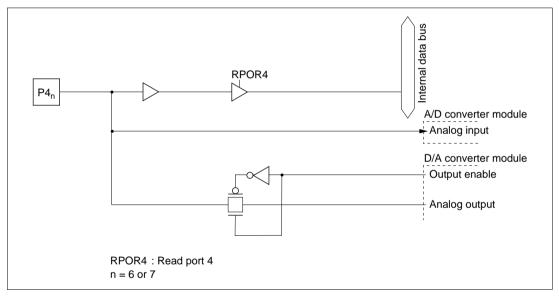


Figure C-4 (b) Port 4 Block Diagram (Pins P46 and P47)

C.5 Port 5 Block Diagram

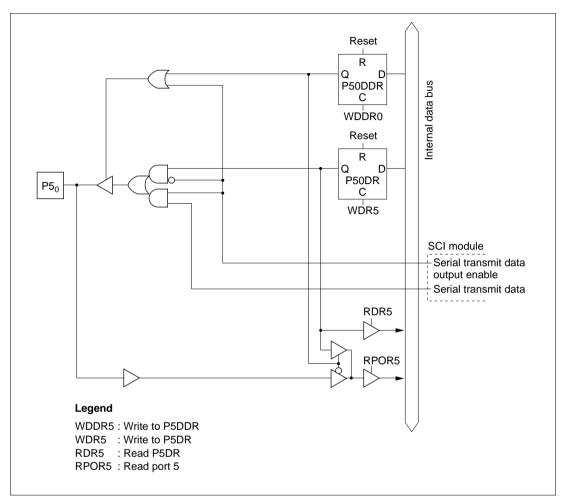
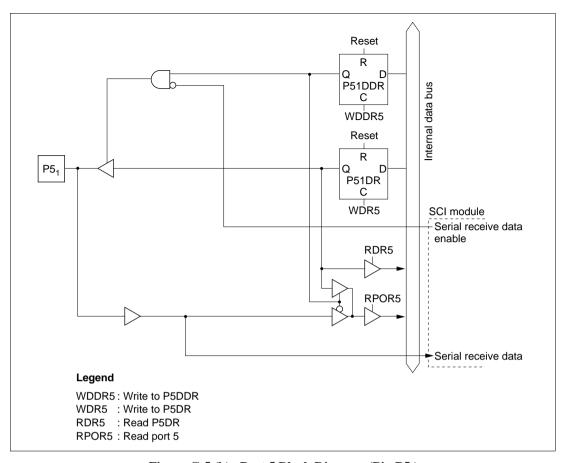


Figure C-5 (a) Port 5 Block Diagram (Pin P5₀)



 $Figure \ C\text{-}5\ (b) \quad Port\ 5\ Block\ Diagram\ (Pin\ P5_1)$

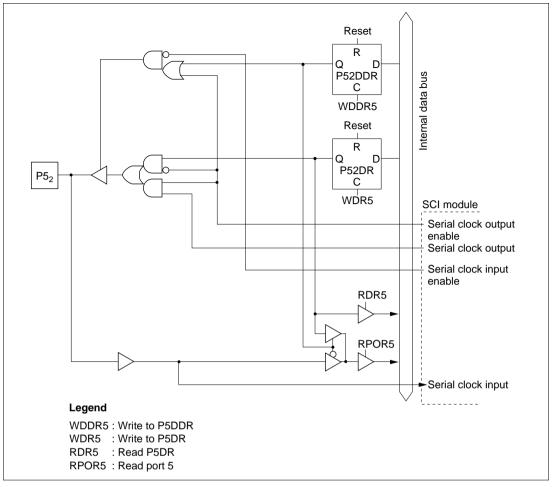


Figure C-5 (c) Port 5 Block Diagram (Pin P5₂)

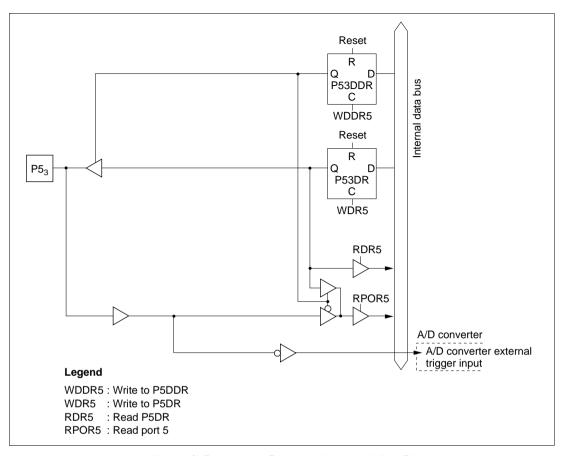


Figure C-5 (d) Port 5 Block Diagram (Pin $P5_3$)

C.6 Port 6 Block Diagram

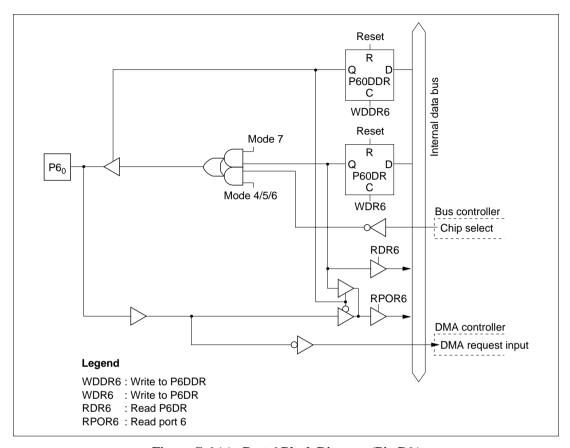


Figure C-6 (a) Port 6 Block Diagram (Pin $P6_0$)

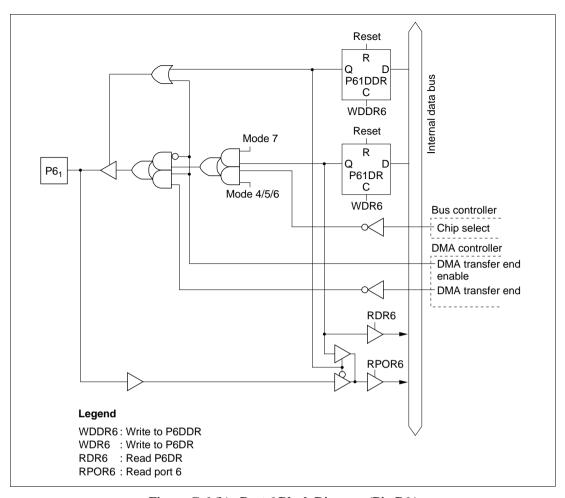


Figure C-6 (b) Port 6 Block Diagram (Pin $P6_1$)

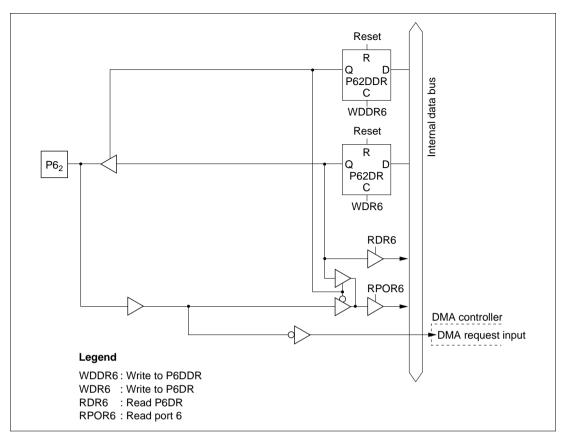
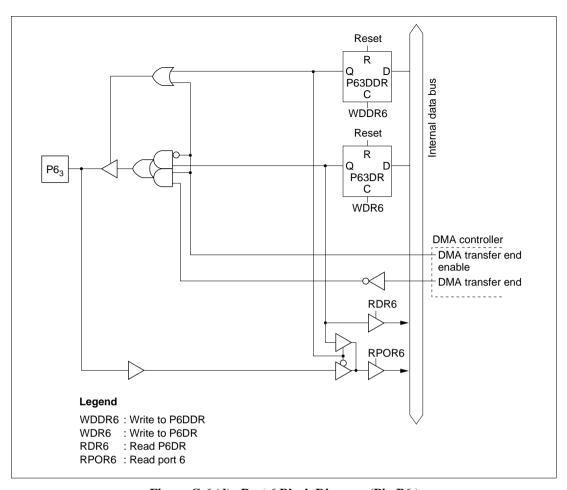


Figure C-6 (c) Port 6 Block Diagram (Pin P6₂)



 $Figure~C\text{-}6~(d)~~Port~6~Block~Diagram~(Pin~P6_3)\\$

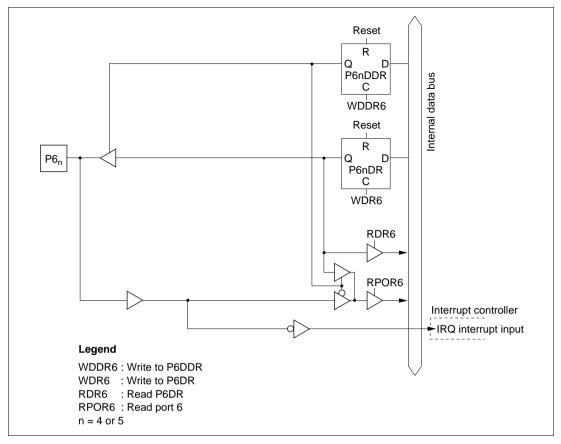


Figure C-6 (e) Port 6 Block Diagram (Pins P6₄ and P6₅)

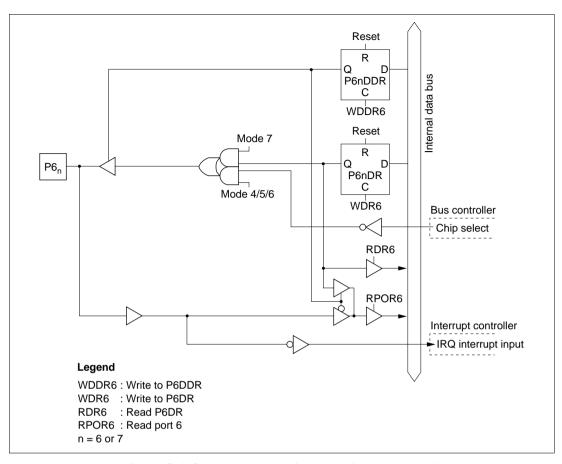


Figure C-6 (f) Port 6 Block Diagram (Pins P6₆ and P6₇)

C.7 Port A Block Diagram

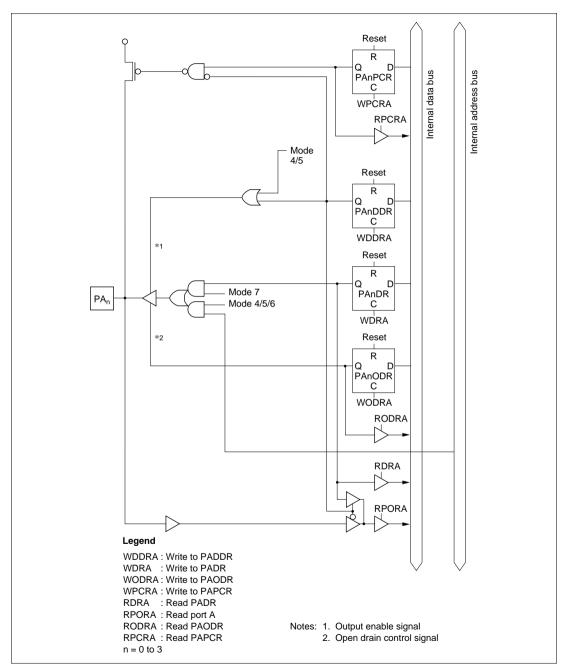


Figure C-7 (a) Port A Block Diagram (Pins PA₀ to PA₃)

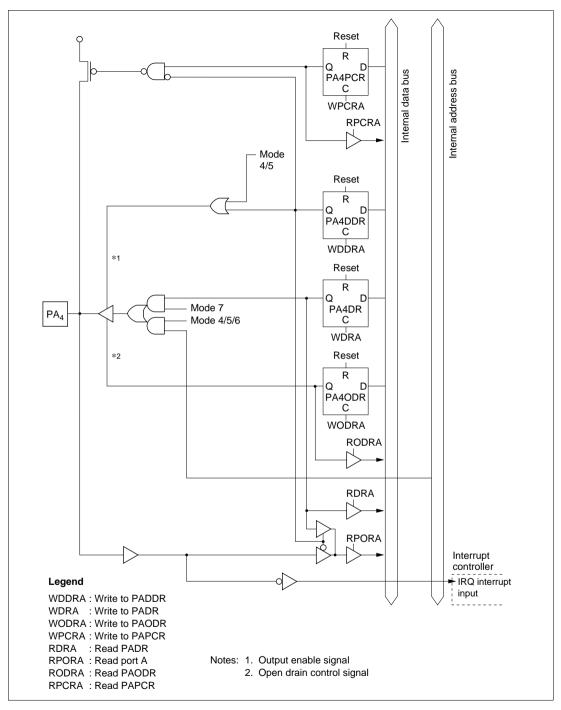


Figure C-7 (b) Port A Block Diagram (Pin PA₄)

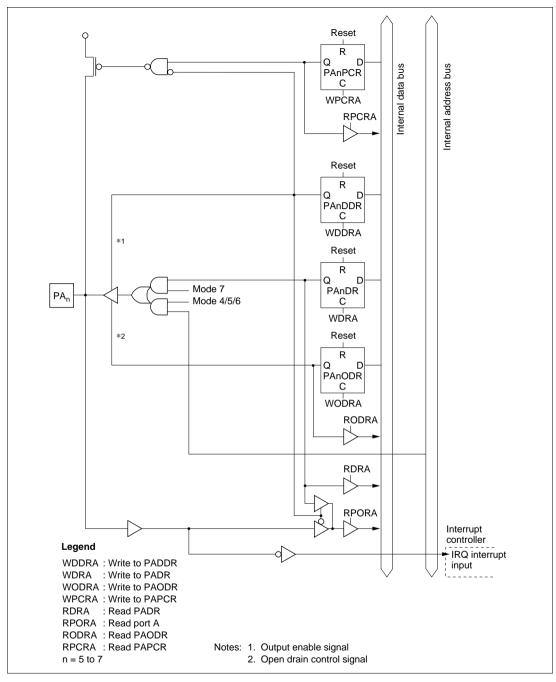
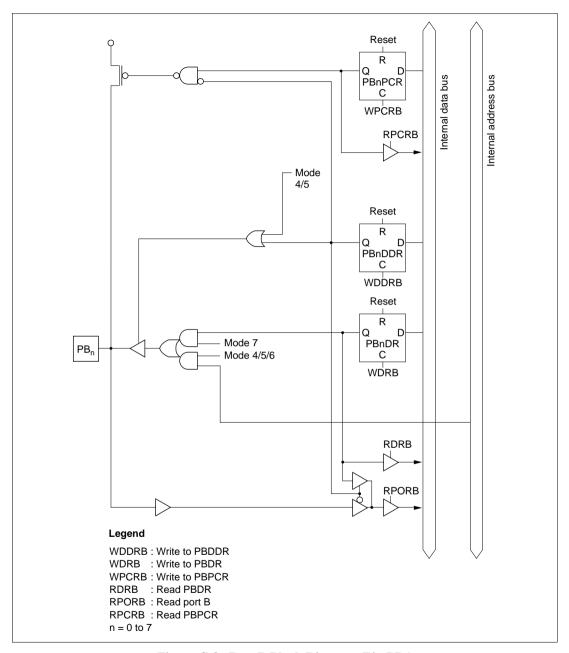


Figure C-7 (c) Port A Block Diagram (Pins PA_5 to PA_7)

C.8 Port B Block Diagram



 $Figure \ C-8 \quad Port \ B \ Block \ Diagram \ (Pin \ PB_n)$

C.9 Port C Block Diagram

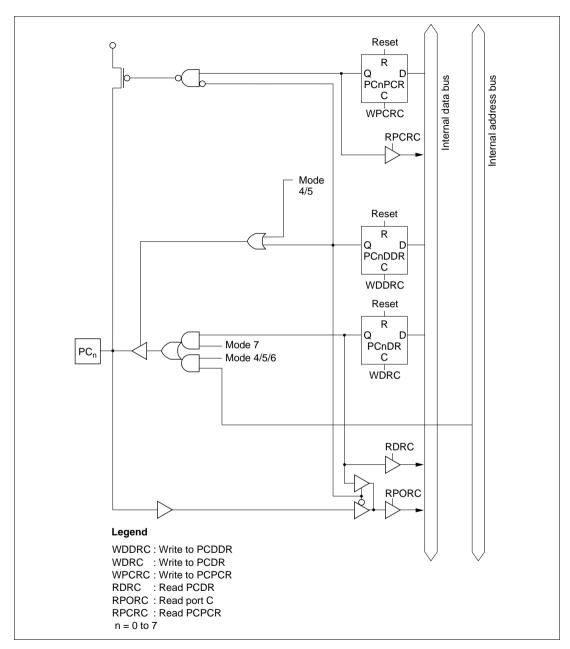
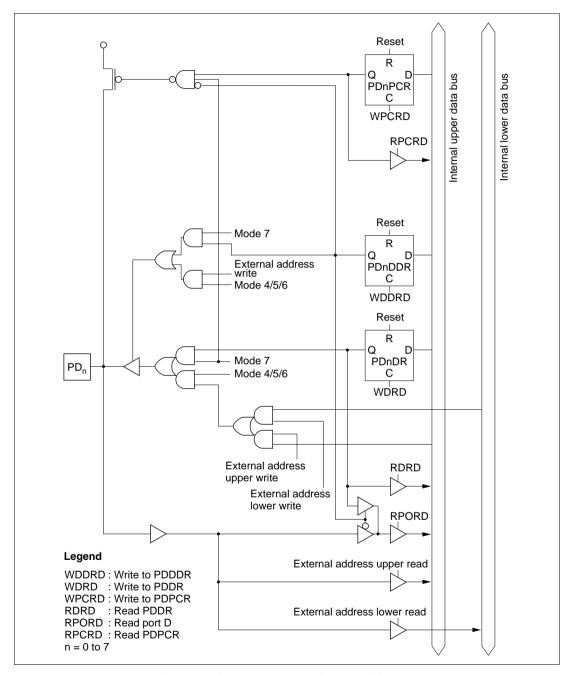


Figure C-9 Port C Block Diagram $(Pin PC_n)$

C.10 Port D Block Diagram



 $Figure \ C\text{-}10 \quad Port \ D \ Block \ Diagram \ (Pin \ PD_n)$

C.11 Port E Block Diagram

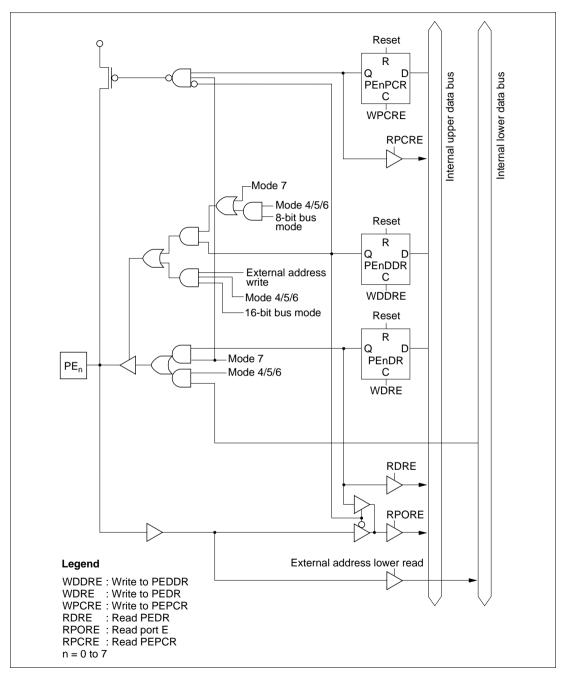


Figure C-11 Port E Block Diagram (Pin PE_n)

C.12 Port F Block Diagram

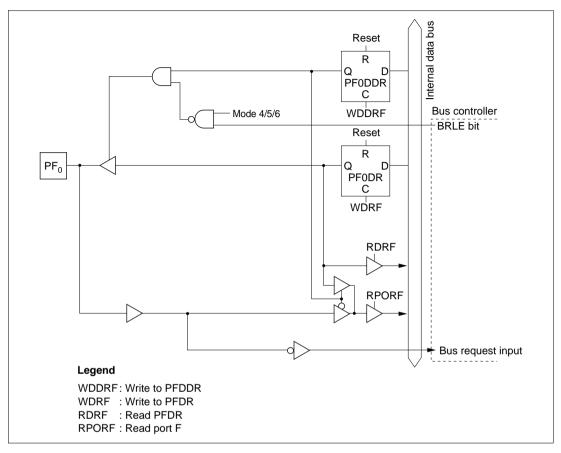
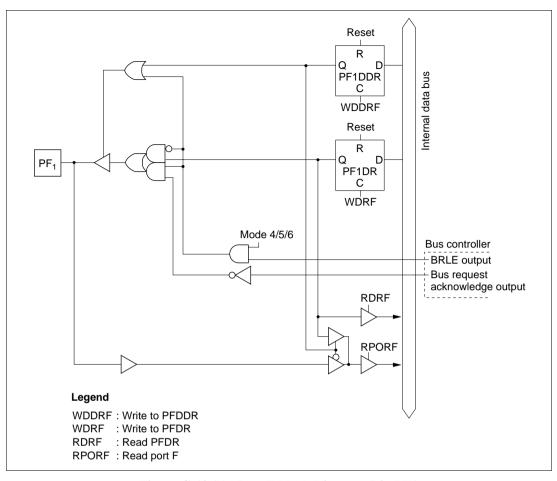


Figure C-12 (a) Port F Block Diagram (Pin PF₀)



 $Figure \ C\text{-}12 \ (b) \quad Port \ F \ Block \ Diagram \ (Pin \ PF_1)$

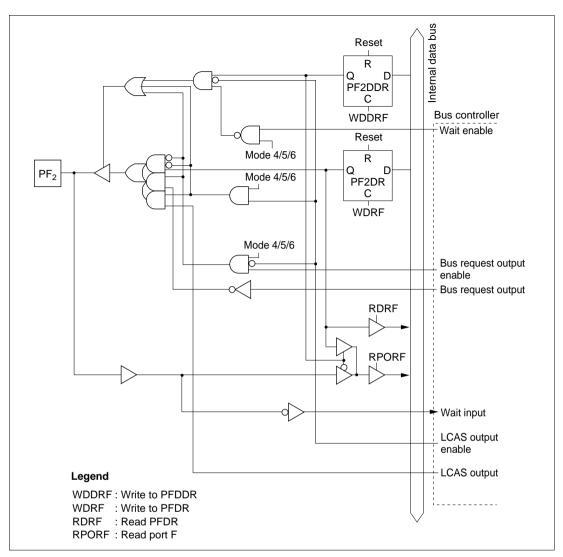


Figure C-12 (c) Port F Block Diagram (Pin PF₂)

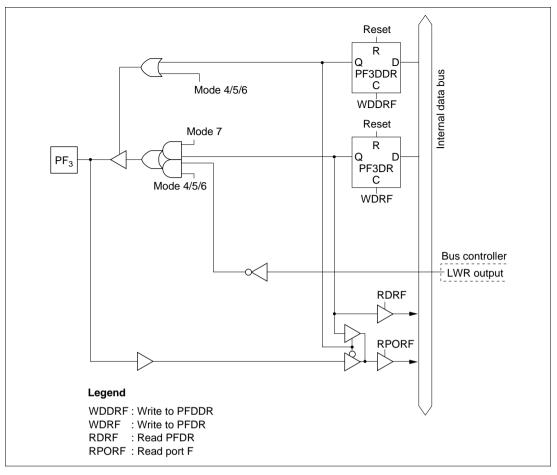


Figure C-12 (d) Port F Block Diagram (Pin PF₃)

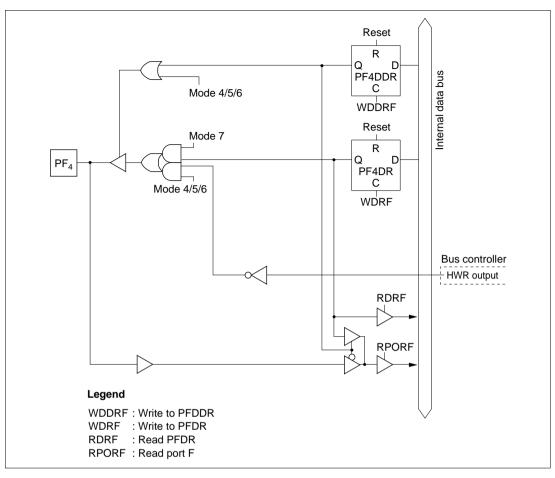


Figure C-12 (e) Port F Block Diagram (Pin PF₄)

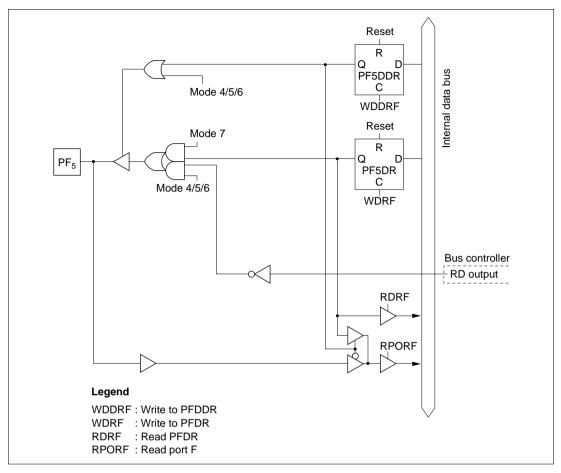
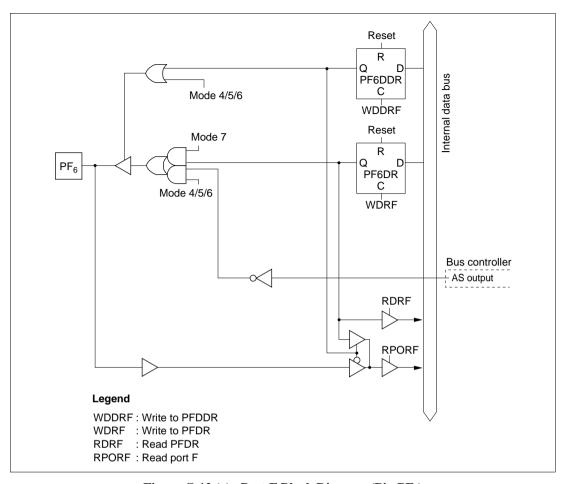


Figure C-12 (f) Port F Block Diagram (Pin PF₅)



 $Figure~C\text{-}12~(g)~~Port~F~Block~Diagram~(Pin~PF_6)$

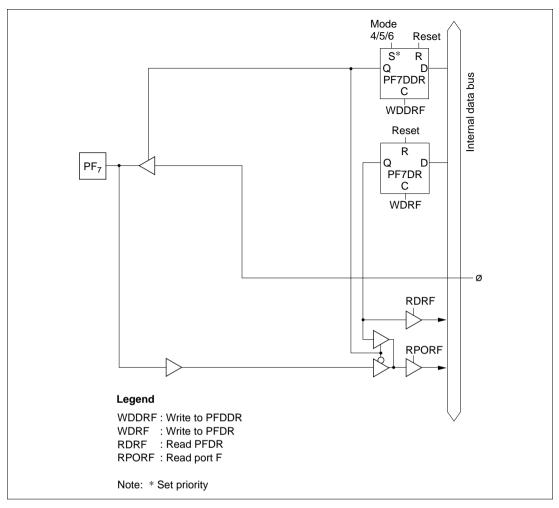


Figure C-12 (h) Port F Block Diagram (Pin PF₇)

C.13 Port G Block Diagram

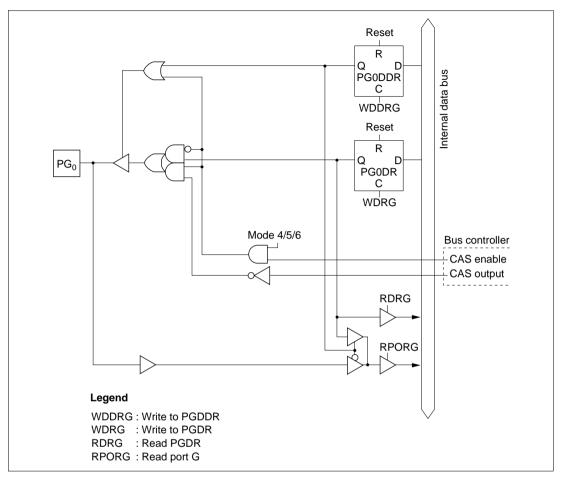


Figure C-13 (a) Port G Block Diagram (Pin PG_0)

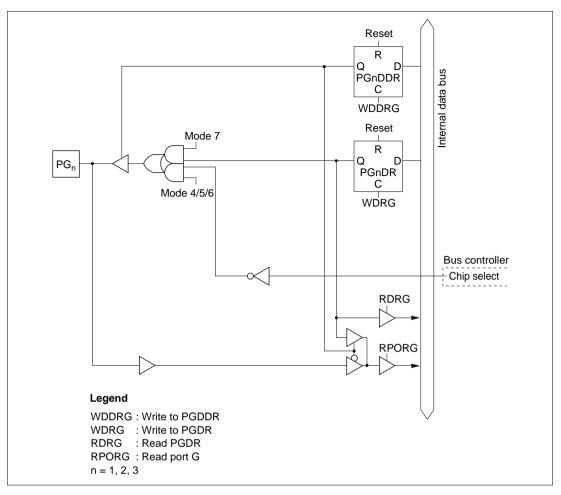


Figure C-13 (b) Port G Block Diagram (Pins PG₁ to PG₃)

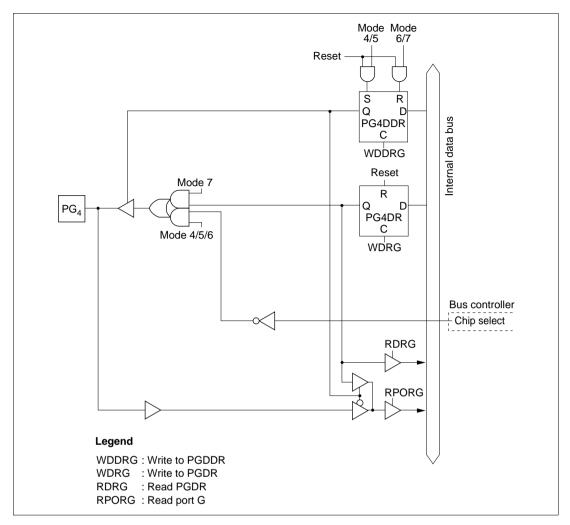


Figure C-13 (c) Port G Block Diagram (Pin PG_4)

Appendix D Pin States

D.1 Port States in Each Mode

Table D-1 I/O Port States in Each Processing State

Port Name Pin Name	MCU Operating Mode	Power- On Reset	Manual Reset* ²	Hardware Standby Mode	Software Standby Mode	Bus Release State	Program Execution State Sleep Mode
Port 1	4 to 7	Т	kept	T	kept	kept	I/O port
Port 2	4 to 7	Т	kept	Т	kept	kept	I/O port
Port 3	4 to 7	Т	kept	Т	kept	kept	I/O port
P4 ₇ /DA1	4 to 7	Т	Т	Т	[DAOE1 = 1] kept [DAOE1 = 0] T	kept	I/O port
P4 ₆ /DA0	4 to 7	Т	Т	Т	[DAOE0 = 1] kept [DAOE0 = 0] T	kept	I/O port
P4 ₅ to P4 ₀	4 to 7	Т	Т	Т	Т	Т	Input port
Port 5	4 to 7	Т	kept	Т	kept	kept	I/O port
P6 ₅ to P6 ₂	4 to 7	Т	kept	Т	kept	kept	I/O port
P6 ₇ /CS7	7	Т	kept	Т	kept	kept	I/O port
P6 ₆ /CS6 P6 ₁ /CS5 P6 ₀ /CS4	4 to 6	Т	kept	Т	$ \begin{aligned} & [DDR \cdot OPE = 0] \\ & T \\ & [DDR \cdot OPE = 1] \\ & H \end{aligned} $	Т	[DDR = 0] Input port [DDR = 1] CS7 to CS4
PA ₇ /A ₂₃ / IRQ7	7	Т	kept	Т	kept	kept	I/O port
$\frac{PA_6/A_{22}}{IRQ6}$ $\frac{PA_5/A_{21}}{IRQ5}$	4, 5	Т	kept	Т	$ [DDR \cdot OPE = 0] $ T $ [DDR \cdot OPE = 1] $ kept	Т	[DDR = 0] Input port [DDR = 1] Address output
PA ₄ /A ₂₀ / IRQ4 PA ₃ /A ₁₉	4, 5	L	kept	Т	[OPE = 0] T [OPE = 1] keep	Т	Address output
PA ₂ /A ₁₈ PA ₁ /A ₁₇ PA ₀ /A ₁₆	6	Т	kept	Т	[DDR · OPE = 0] T [DDR · OPE = 1] kept	Т	[DDR = 0] Input port [DDR = 1] Address output

Port Name Pin Name	MCU Opera Mode	ting	Power- On Reset	Manual Reset* ²	Hardware Standby Mode	Software Standby Mode	Bus Release State	Program Execution State Sleep Mode
Port B	4, 5		L	kept	Т	[OPE = 0] T [OPE = 1] kept	Т	Address output
	6		Т	kept	Т	[DDR · OPE = 0] T [DDR · OPE = 1] kept	Т	[DDR = 0] Input port [DDR = 1] Address output
	7		Т	kept	Т	kept	kept	I/O port
Port C	4, 5		L	kept	Т	[OPE = 0] T [OPE = 1] kept	Т	Address output
	6		Т	kept	Т	[DDR · OPE = 0] T [DDR · OPE = 1] kept	Т	[DDR = 0] Input port [DDR = 1] Address output
	7		Т	kept	Т	kept	kept	I/O port
Port D	4 to 6		Т	T*1	Т	Т	Т	Data bus
	7		Т	kept	Т	kept	kept	I/O port
Port E	4 to 6	8 bit bus	Т	kept	Т	kept	kept	I/O port
		16 bit bus	T	T*1	Т	Т	Т	Data bus
	7		Т	kept	Т	kept	kept	I/O port
PF ₇ /ø	4 to 6		Clock output	[DDR = 0] T [DDR = 1] Clock output	Т	[DDR = 0] Input port [DDR = 1] H	[DDR = 0] Input port [DDR = 1] Clock output	[DDR = 0] Input port [DDR = 1] Clock output
	7		Т	kept	Т	[DDR = 0] Input port [DDR = 1] H	[DDR = 0] Input port [DDR = 1] Clock output	[DDR = 0] Input port [DDR = 1] Clock output

Port Name Pin Name	MCU Operating Mode	Power- On Reset	Manual Reset* ²	Hardware Standby Mode	Software Standby Mode	Bus Release State	Program Execution State Sleep Mode
PF ₆ /AS PF ₅ /RD PF ₄ /HWR PF ₃ /LWR	4 to 6	Н	H* ¹	Т	[OPE = 0] T [OPE = 1] H	Т	AS, RD, HWR, LWR
	7	Т	kept	Т	kept	kept	I/O port
PF ₂ /LCAS/ WAIT/ BREQO	4 to 6	Т	[BREQOE + WAITE + LCASE = 0] kept [BREQOE = 1] BREQO [WAITE = 1] T [LCASE = 1] H*1	T	[BREQOE + WAITE + LCASE = 0] kept [BREQOE = 1] kept [WAITE = 1] T [LCASE = 1, OPE = 0] T [LCASE = 1, OPE = 1] LCAS	[BREQOE + WAITE + LCASE = 0] kept [BREQOE = 1] BREQO [WAITE = 1] T [LCASE = 1] T	[BREQOE + WAITE + LCASE= 0] I/O port [BREQOE = 1] BREQO [WAITE = 1] WAIT [LCASE = 1] LCAS
	7	Т	kept	Т	kept	kept	I/O port
PF ₁ /BACK	4 to 6	Т	[BRLE = 0] kept [BRLE = 1] BACK	Т	[BRLE = 0] kept [BRLE = 1] H	L	[BRLE = 0] I/O port [BRLE = 1] BACK
	7	Т	kept	Т	kept	kept	I/O port
PF ₀ /BREQ	4 to 6	Т	[BRLE = 0] kept [BRLE = 1] BREQ	Т	[BRLE = 0] kept [BRLE = 1] T	Т	[BRLE = 0] I/O port [BRLE = 1] BREQ
$PG_4/\overline{CS0}$	4, 5	Н	[DDR = 0]	Т	$[DDR \cdot OPE = 0]$	Т	[DDR = 0]
	6	T	T [DDR = 1] H* ¹		T [DDR · OPE = 1] H		Input port [DDR = 1] CS0
	7	T	kept	Т	kept	kept	I/O port

Port Name Pin Name	MCU Operating Mode	Power- On Reset	Manual Reset* ²	Hardware Standby Mode	Software Standby Mode	Bus Release State	Program Execution State Sleep Mode
PG ₃ /CS1	7	Т	kept	Т	kept	kept	I/O port
PG ₂ /CS2 PG ₁ /CS3	4 to 6	T	[DDR = 0] T [DDR = 1] H* ¹	Т	$[DDR \cdot OPE = 0]$ T $[DDR \cdot OPE = 1]$ H	Т	[DDR = 0] Input port [DDR = 1] CS1 to CS3
PG0/CAS	7	Т	kept	Т	kept	kept	I/O port
	4 to 6	Т	[DRAME = 0] kept [DRAME = 1] H* ¹	Т	[DRAME = 0] kept [OPE = 0] T [DRAME · OPE= 1] CAS	Т	[DRAME = 0] Input port [DRAME = 1] CAS

Legend:

H : High level L : Low level

T : High impedance

kept : Input port becomes high-impedance, output port retains state

DDR : Data direction register
OPE : Output port enable
WAITE : Wait input enable
BRLE : Bus release enable
BREQOE : BREQO pin enable
DRAME : DRAM space setting

LCASE : DRAM space setting, CW2 = LCASS = 0

Notes: 1. Indicates the state after completion of the executing bus cycle.

2. Manual reset is only supported in the H8S/2357-ZTAT version.

Appendix E Pin States at Power-On

Note that pin states at power-on depend on the state of the \overline{STBY} pin and NMI pin. The case in which pins settle* from an indeterminate state at power-on, and the case in which pins settle* from the high-impedance state, are described below.

After reset release, power-on reset exception handling is started.

Note: * "Settle" refers to the pin states in a power-on reset in each MCU operating mode.

E.1 When Pins Settle from an Indeterminate State at Power-On

When the NMI pin level changes from low to high after powering on, the chip goes to the poweron reset state*2 after a high level is detected at the NMI pin. While the chip detects a low level at the NMI pin, the manual reset state*1 is established. The pin states are indeterminate during this interval. (Ports may output an internally determined value after powering on.)

The NMI setup time (t_{NMIS}) is necessary for the chip to detect a high level at the NMI pin.

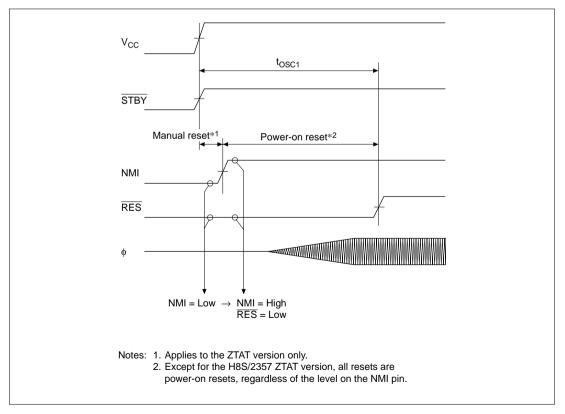


Figure E-1 When Pins Settle from an Indeterminate State at Power-On

E.2 When Pins Settle from the High-Impedance State at Power-On

When the \overline{STBY} pin level changes from low to high after powering on, the chip goes to the power-on reset state*2 after a high level is detected at the \overline{STBY} pin. While the chip detects a low level at the \overline{STBY} pin, it is in the hardware standby mode. During this interval, the pins are in the high-impedance state.

After detecting a high level at the \overline{STBY} pin, the chip starts oscillation.

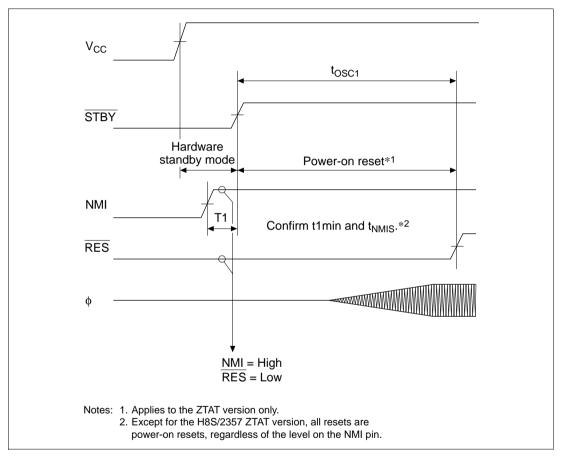


Figure E-2 When Pins Settle from the High-Impedance State at Power-On

Appendix F Timing of Transition to and Recovery from Hardware Standby Mode

F.1 Timing of Transition to Hardware Standby Mode

(1) To retain RAM contents with the RAME bit set to 1 in SYSCR, drive the RES signal low at least 10 states before the STBY signal goes low, as shown below. RES must remain low until STBY signal goes low (delay from STBY low to RES high: 0 ns or more).

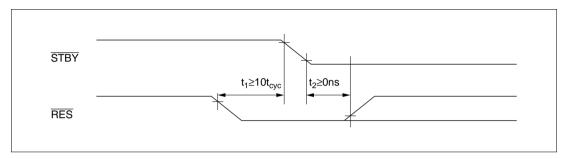


Figure F-1 Timing of Transition to Hardware Standby Mode

(2) To retain RAM contents with the RAME bit cleared to 0 in SYSCR, or when RAM contents do not need to be retained, RES does not have to be driven low as in (1).

F.2 Timing of Recovery from Hardware Standby Mode

Drive the \overline{RES} signal low and the NMI signal high approximately 100 ns or more before \overline{STBY} goes high to execute a power-on reset.

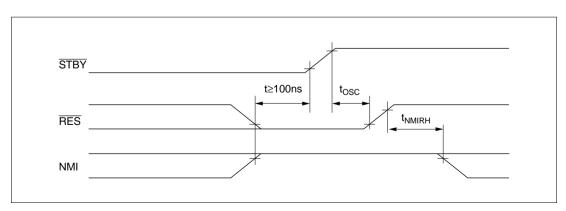


Figure F-2 Timing of Recovery from Hardware Standby Mode

Appendix G Product Code Lineup

Table G.1 H8S/2357, H8S/2352 Product Code Lineup

Product Typ	oe .	Product Code Mark Code		Package (Hitachi Package Code)	
H8S/2357	Mask ROM	HD6432357	HD6432357TE	120-pin TQFP (TFP-120)	
			HD6432357F	128-pin QFP (FP-128)	
	ZTAT™	HD6472357	HD6472357TE	120-pin TQFP (TFP-120)	
			HD6472357F	128-pin QFP (FP-128)	
	F-ZTAT™	HD64F2357	HD64F2357TE	120-pin TQFP (TFP-120)	
			HD64F2357F	128-pin QFP (FP-128)	
H8S/2352	ROMless	HD6412352	HD6412352TE	120-pin TQFP (TFP-120)	
			HD6412352F	128-pin QFP (FP-128)	

Table G.2 H8S/2398, H8S/2396, H8S/2395, H8S/2394, H8S/2392, H8S/2390 Series Product Code Lineup

Product Type		Product Code	Mark Code	Package (Hitachi Package Code)	
H8S/2398	Mask-ROM	HD6432398	HD6432398TE*1	120-pin TQFP (TFP-120)	
			HD6432398F* ¹	128-pin QFP (FP-128)	
	F-ZTAT™	HD64F2398	HD64F2398TE*1	120-pin TQFP (TFP-120)	
			HD64F2398F* ¹	128-pin QFP (FP-128)	
H8S/2396	F-ZTAT™	HD64F2396	HD64F2396TE*2	120-pin TQFP (TFP-120)	
			HD64F2396F*2	128-pin QFP (FP-128)	
H8S2395	F-ZTAT™	HD64F2395	HD64F2395TE*2	120-pin TQFP (TFP-120)	
			HD64F2395F*2	128-pin QFP (FP-128)	
H8S/2394	ROMless	HD6412394	HD6412394TE*1	120-pin TQFP (TFP-120)	
			HD6412394F*1	128-pin QFP (FP-128)	
H8S/2392	ROMless	HD6412392	HD6412392TE	120-pin TQFP (TFP-120)	
			HD6412392F	128-pin QFP (FP-128)	
H8S/2390	ROMless	HD6412390	HD6412390TE	120-pin TQFP (TFP-120)	
			HD6412390F	128-pin QFP (FP-128)	

Note: *1 Under development.

^{*2} In Planning.

Appendix H Package Dimensions

Figures H-1 and H-2 show the TFP-120 and FP-128 package dimensions of the H8S/2357 Series.

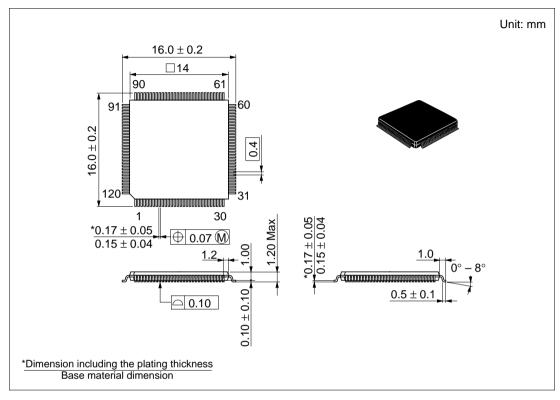


Figure H-1 TFP-120 Package Dimensions

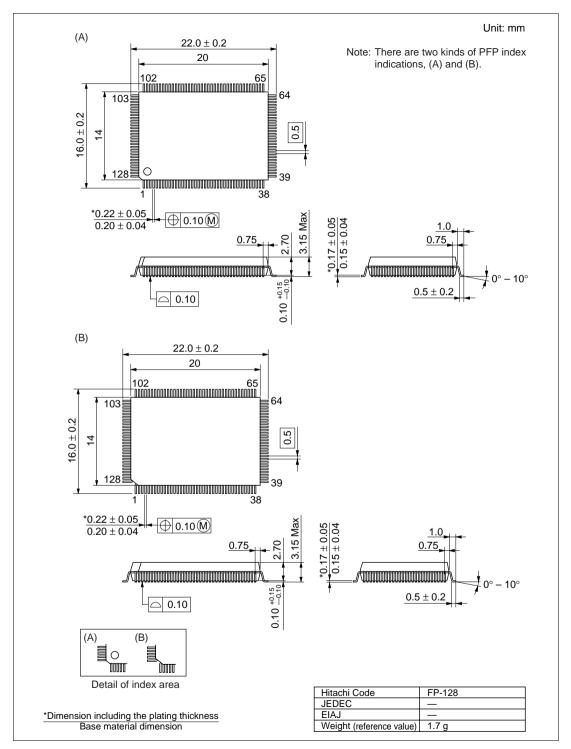


Figure H-2 FP-128 Package Dimensions

H8S/2357 Series, H8S/2357 F-ZTATTM, H8S/2395 F-ZTATTM, H8S/2396 F-ZTATTM, H8S/2398 F-ZTATTM, Hardware Manual

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